

## CMOS DATABOOK

## Introduction

This Databook contains information on National Semiconductor's standard SSI/MSI CMOS products. This includes the popular 54C/74C series logic family, which is pin for pin, function for function equivalent to the 7400 family of TTL devices. All device outputs are LPTTL compatible, capable of sinking more than $360 \mu \mathrm{~A}$ ( $\approx 1$ LSTTL load). The AC parameters are specified with a 50 pF capacitive load.
In addition this book describes National Semiconductor's extensive line of CD40XXB and CD45XXB series devices. These parts meet the standard JEDEC "B-Series" specifications.

Special Function, LSI, A/D Converters and Memory device specifications contained herein offer the designer unique high density low power system solutions. All devices are compatible with 54C/74C series and CD4XXB series products.

> MM54CXX/MM74CXX Series Logic MM54C9XX MM74C9XX Special Function/LSI Devices

> CMOS A/D Converters

CMOS Memory

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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# CMOS Microprocessor and Support Circuits (see NSC800 Databook) 

NSC800 High Performance Low Power Microprocessor
NSC810 RAM-I/O-Timer
NSC830 ROM-I/O
NSC831 I/O

## MOS/LSI CMOS Circuits <br> (see MOS/LSI Databook for data sheets.)

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| Device Type/Description | $\begin{aligned} & \mathrm{C}_{\text {PD }}(\mathrm{pF}) \\ & \text { (Note 3) } \end{aligned}$ | $\begin{gathered} \mathrm{t}_{\mathrm{PD}}(\mathrm{~ns}) \\ \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V} \end{gathered}$ | $\Delta t_{P D}$ Curve | FANOUT |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | LP | LS | TTL |
| MM54C00/MM74C00 Quad 2-Input NAND Gate | 12 | 50 | A | 2 | 1 | - |
| MM54C02/MM74C02 Quad 2-Input NOR Gate | 12 | 50 | A | 2 | 1 | - |
| MM54C04/MM74C04 Hex Inverter | 12 | 50 | A | 2 | 1 | - |
| MM54C08/MM74C08 Quad 2-Input AND Gate | 14 | 80 | A | 2 | 1 | - |
| MM54C10/MM74C10 Triple 3-Input NAND Gate | 18 | 60 | A | 2 | 1 | - |
| MM54C14/MM74C14 Hex Schmitt Trigger | 20 | 220 | A | 2 | 1 | - |
| MM54C20/MM74C20 Dual 4-Input NAND Gate | 30 | 70 | A | 2 | 1 | - |
| MM54C30/MM74C30 8-Input NAND Gate | 26 | 125 | A | 2 | 1 | - |
| MM54C32/MM74C32 Quad 2-Input OR Gate | 15 | 80 | A | 2 | 1 | - |
| MM54C42/MM74C42 BCD-to-Decimal Decoder | 50 | 200 | A | 2 | 1 | - |
| MM54C48/MM74C48 BCD-to-7-Segment Decoder | NA | 450(1) | NA | 2 | 1 | - |
| MM54C73/MM74C73 Dual J-K Flip-Flops | 40 | 180 | A | 2 | 1 | - |
| MM54C74/MM74C74 Dual D Flip-Flop | 40 | 180 | A | 2 | 1 | - |
| MM54C76/MM74C76 Dual J-K Flip-Flops | 40 | 180 | A | 2 | 1 | - |
| MM54C83/MM74C83 4-Bit Binary Full Adder | 120 | 300 | A | 2 | 1 | - |
| MM54C85/MM74C85 4-Bit Magnitude Comparator | 45 | 220 | A | 2 | 1 | - |
| MM54C86/MM74C86 Quad 2-Input | 20 | 110 | A | 2 | 1 | - |
| MM54C89/MM74C89 64-Bit RAM | 230 | 270 | A | 2 | 1 | - |
| MM54C90/MM74C90 4-Bit Decade Counter | 45 | 400 | A | 2 | 1 | - |
| MM54C93/MM74C93 4-Bit Binary Counter | 45 | 400 | A | 2 | 1 | - |
| MM54C95/MM74C95 4-Bit Shift Register | 100 | 200 | A | 2 | 1 | - |
| MM54C107/MM74C107 Dual J-K Flip-Flops | 40 | 180 | A | 2 | 1 | - |
| MM54C150/MM74C150 16-Line to 1-Line Multiplexer | 100 | 250 | A | 10 | 5 | 1 |
| MM54C151/MM74C151 8-Channel Digital Multiplexer | 50 | 200(1) | A | 2 | 1 | - |
| MM54C154/MM74C154 4-16 Decoder/Demultiplexer | 60 | 275(1) | A | 2 | 1 | - |
| MM54C157/MM74C157 Quad 2-Input Multiplexer | 20 | 150(1) | A | 2 | 1 | - |
| MM54C160/MM74C160 Decade Counter | 95 | 250(2) | A | 2 | 1 | - |
| MM54C161/MM74C161 Binary Counter | 95 | 250(2) | A | 2 | 1 | - |
| MM54C162/MM74C162 Decade Counter | 95 | 250(2) | A | 2 | 1 | - |
| MM54C163/MM74C163 Binary Counter | 95 | 250(2) | A | 2 | 1 | - |
| -MM54C164/MM74C164 8-Bit Shift Register | 140 | 230(2) | A | 2 | 1 | - |
| MM54C165/MM74C165 8-Bit Shift Register | 55 | 210(2) | A | 2 | 1 | - |
| MM54C173/MM74C173 TRI-STATE® ${ }^{\text {® }}$ Quad D Flip-Flop | 100 | 220(2) | A | 2 | 1 | - |
| MM54C174/MM74C174 Hex D Flip-Flop | 95 | 150(2) | A | 2 | 1 | - |
| MM54C175/MM74C175 Quad D Flip-Flop | 130 | 190(2) | A | 2 | 1 | - |
| MM54C192/MM74C192 Decade Up/Down Counter | 100 | 250(2) | A | 2 | 1 | - |
| MM54C193/MM74C193 Binary Up/Down Counter | 100 | 250(2) | A | 2 | 1 | - |
| MM54C195/MM74C195 4-Bit Register | 130 | 200(2) | A | 2 | 1 | - |
| MM54C200/MM74C200 256-Bit RAM | 400 | 850 | A | 2 | 1 | - |
| MM54C221/MM74C221 Dual Monostable Multivibrator | NA | 250 | A | 2 | 1 | - |
| MM54C240/MM74C240 Octal Buffers | 100 | 60 | B | 13 | 6 | 1 |
| MM54C244/MM74C244 Octal Buffers | 100 | 45 | B | 13 | 6 | 1 |
| MM54C373/MM74C373 Octal Latch | 200 | 165 | B | 10 | 5 | 1 |
| MM54C374/MM74C374 Octal D-Type Flip-Flop | 250 | 165 | B | 10 | 5 | 1 |
| MM54C901/MM74C901 Hex Inverting TTL Buffer | 30 | 38 | B | 2 | 1 | - |
| MM54C902/MM74C902 Hex Non-Inverting TTL Buffer | 50 | 57 | B | 2 | 1 | - |
| MM54C903/MM74C903 Hex Inverting PMOS Buffer | 30 | 57 | B | 2 | 1 | - |
| MM54C904/MM74C904 Hex Non-Inverting PMOS Buffer | 50 | 38 | B | 2 | 1 | - |
| MM54C905/MM74C905 12-Bit SAR | 100 | 200 | A | 2 | 1 | - |
| MM54C906/MM74C906 Hex Open Drain Buffer | 30 | NA | NA | 2 | 1 | - |
| MM54C907/MM74C907 Hex Open Drain Buffer | 30 | NA | NA | 2 | 1 | - |
| MM74C908 Dual CMOS 30 Volt Driver | NA | 150 | NA | NA | NA | NA |
| MM54C914/MM74C914 Hex Schmitt Trigger | 20 | 220 | A | 2 | 1 | - |
| MM54C915/MM74C915 7-Segment-to-BCD Converter | NA | 150 | NA | 10 | 5 | 1 |
| MM54C918 Dual CMOS 30 Volt Driver | NA | 60 | B | NA | NA | NA |
| MM54C922/MM74C922 16-Key Encoder | NA | NA | B | 2 | 1 | - |
| MM54C923/MM74C923 20-Key Encoder | NA | NA | B | 2 | 1 | - |


| Device Type/Description | $C_{\text {PD }}$ (pF) <br> (Note 3) | $\begin{gathered} \mathrm{t}_{\mathrm{PD}}(\mathrm{~ns}) \\ \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V} \end{gathered}$ | $\Delta t_{p D^{\prime}}$ Curve | FANOUT |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | LP | LS | TTL |
| MM54C932/MM74C932 Phase Comparator | NA | NA | B | NA | NA | NA |
| MM54C941/MM74C941 Octal Buffer | 100 | 70 | B | 13 | 6 | 1 |
| MM70C95/MM80C95 TRI-STATE® Hex Buffers | 60 | 60 | B | 10 | 5 | 1 |
| MM70C96/MM80C96 TRI-STATE Hex Inverters | 60 | 70 | B | 10 | 5 | 1 |
| MM70C97/MM80C97 TRI-STATE Hex Buffers | 60 | 60 | B | 10 | 5 | 1 |
| MM70C98/MM80C98 TRI-STATE Hex Inverters | 60 | 70 | B | 10 | 5 | 1 |
| MM72C19/MM82C19 TRI-STATE 16-1 Multiplexer | 100 | 250 | A | 10 | 5 | 1 |
| MM78C29/MM88C29 Quad Single-Ended Line Driver | 150 | 200 | NA | NA | NA | NA |
| MM78C30/MM88C30 Dual Differential Line Driver | 200 | 350 | NA | NA | NA | NA |

Note 1: $t_{\text {PD }}$ shown is from data input to output. For more detailed specifications see individual data sheet.
Note 2: $t_{\text {PD }}$ shown is from clock to output. For more detailed specifications see individual data sheet.
Note 3: $\mathrm{C}_{\text {PD }}$ numbers shown are for independent identical functions within a package. For instance the total $\mathrm{C}_{\text {PD }}$ for a MM74C157 is $4 \times 20 \mathrm{pF}=80 \mathrm{pF}$ while the total $\mathrm{C}_{\mathrm{PD}}$ for the MM74C173 is 100 pF because all flip-flops have a common clock.


For complete explanation on use of curves see application note AN-90,54C/74C Family Characteristics.

## National Semiconductor's Megarad Radiation Hardened Product List

The following device types are currently available from National Semiconductor as a radiation hardened product to the $10^{6}$ RADS $(\mathrm{Si})$ level. These parts will be processed to National's 883 S /RETS flow in the bottom braised flat (F) or side braised dual-in-line (D) packages.

RAD Hard CMOS

| Device | Series | Device | Series | Device | Series | Device | Series | Device |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CD4001 | A/B | CD4019 | B | CD4042 | B | CD4075 | B | MM54C04 |
| CD4002 | A | CD4020 | A | CD4043 | A | CD4076 | B | MM54C14 |
| CD4006 | A | CD4021 | A | CD4044 | A | CD4081 | B | MM54C86 |
| CD4007 | A | CD4022 | B | CD4048 | B | CD4093 | B | MM54C173 |
| CD4008 | B | CD4023 | A/B | CD4049 | A | CD4099 | B | MM54C174 |
| CD4009 | A | CD4024 | B | CD4050 | B | CD40106 | B | MM54C192 |
| CD4010 | A | CD4025 | A/B | CD4051 | B | CD40174 | B | MM54C193 |
| CD4011 | A | CD4027 | B | CD4052 | B | CD40192 | B | MM54C200 |
| CD4012 | A | CD4028 | B | CD4053 | B | CD40193 | B | MM54C901 |
| CD4013 | B | CD4029 | B | CD4066 | B | CD4514 | B | MM54C902 |
| CD4014 | A | CD4030 | A | CD4069 | A | CD4515 | B | MM54C903 |
| CD4015 | A | CD4031 | B | CD4070 | B | CD4518 | B | MM54C904 |
| CD4016 | A | CD4035 | B | CD4071 | B | CD4520 | B | MM54C906 |
| CD4017 | B | CD4040 | A | CD4073 | B | CD4584 | B | MM54C907 |
| CD4018 | B | CD4041 | A |  |  |  |  |  |

Cross Reference Guide
A Listing of CD4000 Series Parts that make up the National Semiconductor family, with competitor equivalents, for easy reference

| Product | Description | RCA | Motorola | Fairchild |
| :---: | :---: | :---: | :---: | :---: |
| CD4000 | Dual 3-Input NOR Gate Plus Inverter | CD4000 | MC14000 | - |
| CD4001 | Quad 2-Input NOR Gate | CD4001 | MC14001 | - |
| CD4001B | Buffered Quad 2-Input NOR Gate | CD4001B | MC14001B | 4001B |
| CD4002 | Dual 4-Input NOR Gate | CD4002 | MC14002 | - |
| CD4002B | Dual Buffered 4-Input NOR Gate | CD4002B | MC14002B | - |
| CD4006B | 18-Bit S/R | CD4006B | MC14006B | 4006B |
| CD4007 | Dual Complementary Pair Plus Inverter | CD4007 | MC14007 | 4007 |
| CD4008B | 4-Bit Full Adder with Parallel Carry | CD4008B | MC14008B | 4008B |
| CD4009 | Hex Inverting Buffer | CD4009 | - | - |
| CD4010 | Hex Buffer | CD4010 | - | - |
| CD4011 | Quad 2-Input NAND Gate | CD4011 | MC14011 | 4011 |
| CD4011B | Buffered Quad 2-Input NAND Gate | CD4011B | MC14011B | 4011B |
| CD4012 | Dual 4-Input NAND Gate | CD4012 | MC14012 | - |
| CD4012B | Dual Buffered 4-Input NAND Gate | CD4012B | MC14012B | - |
| CD4013B | Dual D Flip-Flop | CD4013B | MC14013B | 4013B |
| CD4014B | 8-Bit S/R | CD4014B | MC14014B | 4014B |
| CD4015B | Dual 4-Bit S/R | CD4015B | MC14015B | 4015B |
| CD4016B | Quad Bilateral Switch | CD4016B | MC14016B | 4016B |
| CD4017B | Decade Counter Divider | CD4017B | MC14017B | 4017B |
| CD4018B | Presettable Divide by "N" Counter | CD4018B | MC14018B | 4018B |
| CD4019B | Quad ANDIOR Select Gate | CD4019B | - | 4019B |
| CD4020B | 14-Bit Ripple Carry Binary Counter/Divider | CD4020B | MC14020B | 4020B |
| CD4021B | 8-Bit S/R | CD4021B | MC14021B | 4021B |
| CD4022B | Divide-by-8 Counter Divider | CD4022B | MC14022B | 4022B |
| CD4023 | Triple 3-Input NAND Gate | CD4023 | MC14023 | 4023 |
| CD4023B | Buffered Triple 3-Input NAND Gate | CD4023B | MC14023B | 4023B |
| CD4024B | 7-Bit Binary Counter | CD4024B | MC14024B | 4024B |
| CD4025 | Triple 3-Input NOR Gate | CD4025 | MC14025 | - |
| CD4025B | Double Buffered Triple 3-Input NOR Gate | CD4025B | MC14025B | 4025B |
| CD4027B | Dual J-K Flip-Flop | CD4027B | MC14027B | 4027B |
| CD4028B | BCD-to-Decimal Decoder | CD4028B | MC14028B | 4028B |
| CD4029B | Presettable Up/Down Counter | CD4029B | MC14029B | 4029B |
| CD4030 | Quad EX-OR Gate (dual marked as MM74C86) | CD4030 | MC14030 | 4030B |
| CD4031B | 64-Bit S/R | CD4031B | MC14031B | - |
| CD4034B | 8 Bit S/R | CD4034B | MC14034B | 4034B |
| CD4035B | 4-Bit P-In-P-Out S/R | CD4035B | MC14035B | 4035B |
| CD4040B | 12-Bit Binary/Ripple Counter | CD4040B | MC14040B | 4040B |
| CD4041 | Quad True/Complement Buffer | CD4041UB | - | 4041B |
| CD4042B | Quad D Latch | CD4042B | MC14042B | 4042B |
| CD4043B | Quad 3-State NOR R/S Latch | CD4043B | MC14043B | 4043B |
| CD4044B | Quad 3-State NAND R/S Latch | CD4044B | MC14044B | 4044B |
| CD4046B | Phase-Locked Loop | CD4046B | MC14046B | - |
| CD4047B | Monostable-Astable Multivibrator | CD4047B | - | 4047B |
| CD4048B | Expandable 8-Input Gate | CD4048B | MC14048B | 4048B |
| CD4049 | Hex Inverting Buffer | CD4049UB | MC14049UB | 4049B |
| CD4050B | Hex Buffer | CD4050B | MC14050B | 4050B |
| CD4051B | Single 8-Channel Multiplexer | CD4051B | MC14051B | 4051B |
| CD4052B | Differential 4-Channel Multiplexer | CD4052B | MC14052B | 4052B |
| CD4053B | Triple 2-Channel Multiplexer | CD4053B | MC14053B | 4053B |
| CD4060B | 14-Stage Ripple Carry Binary Counter \& Osc. | CD4060B | MC14060B | - |
| CD4066B | Quad Bilateral Switch | CD4066B | MC14066B | 4066B |
| CD4069 | Hex Inverter (dual marked as MM74C04) | CD4069UB | MC14069UB | 4069 |


| Product | Description | RCA | Motorola | Fairchild |
| :---: | :---: | :---: | :---: | :---: |
| CD4070B | Quad Exclusive-OR Gate (dual marked as MM74C86) | CD4070B | MC14070B | 4070B |
| CD4071B | Quad 2-Input OR Gate | CD4071B | MC14071B | 4071B |
| CD4072B | Dual 4-Input OR Gate Buffered B Series | CD4072B | MC14072B | - |
| CD4073B | Triple 3-Input AND Gate | CD4073B | MC14073B | 4073B |
| CD4075B | Triple 3-Input OR Gate | CD4075B | MC14075B | 4075B |
| CD4076B | TRI-STATE ${ }^{\text {® }}$ Quad D Flip-Flop (dual marked as MM74C173) | CD4076B | MC14076B | 4076B |
| CD4081B | Quad 2-Input AND Gate | CD4081B | MC14081B | 4081B |
| CD4082B | Dual 4-Input OR Gate Buffered B Series | CD4082B | MC14082B | - |
| CD4089B | Binary Rate Multiplier | CD4089B | - | - |
| CD4093B | Quad 2-Input NAND Schmitt Trigger | CD4093B | MC14093B | 4093B |
| CD4099B | 8-Bit Addressable Latch | CD4099B | MC14099B | 4099B |
| CD40106B | Hex Schmitt Trigger (dual marked as MM74C14) | CD40106B | MC14584B | 40014 |
| CD40160B | Sync Decade Counter (dual marked as MM74C160) | CD40160B | MC14160B | - |
| CD40161B | Sync Binary Counter (dual marked as MM74C161) | CD40161B | MC14161B | 40161B |
| CD40162B | Fully Sync Decade Counter (dual marked as MM74C162) | CD40162B | MC14162B | - |
| CD40163B | Fully Sync Binary Counter (dual marked as MM74C163) | CD40163B | MC14163B | 40163B |
| CD40174B | Hex D Flip-Flop (dual marked as MM74C174) | CD40174B | MC14174B | 40174B |
| CD40175B | Quad D Flip-Flop (dual marked as MM74C175) | - | MC14175B | 40175B |
| CD40192B | Sync Up/Down Decade Counter(dual marked as MM74C192) | CD40192B | - | - |
| CD40193B | Sync Up/Down Binary Counter (dual marked as MM74C193) | CD40193B | MC140193B | 40193B |
| CD4503B | Hex Bus Driver (dual marked as MM80C97) | CD4503B | MC14503B | 40097 |
| CD4510B | BCD Up/Down Counter | CD4510B | MC14510B | 4510B |
| CD4511B | BCD-to-7 Segment Latch/Decoder/Driver | CD4511B | MC14511B | 4511B |
| CD4512B | 8-Channel Data Selector | CD4512B | MC14512B | 4512B |
| CD4514B | 4-Bit Latch/4 to 16 Line Decoder (High) | CD4514B | MC14514B | 4514B |
| CD4515B | 4-Bit Latch/4 to 16 Line Decoder (Low) | CD4515B | MC14515B | 4515B |
| CD4516B | Binary Up/Down Counter | CD4516B | MC14516B | 4516B |
| CD4518B | Dual BCD Up Counter | CD4518B | MC14518B | 4518B |
| CD4519B | 4-Bit AND/OR Selector | - | MC14519B | 4519B |
| CD4520B | Dual Binary Up Counter | CD4520B | MC14520B | 4520B |
| CD4522B | Programmable Divide-by-N Counter (BCD) | - | MC14522B | - |
| CD4526B | Programmable Divide-by-N Counter (Binary) | - | MC14526B | - |
| CD4527B | BCD Rate/Multiplier | CD4527B | MC14527B | - |
| CD4528B | Dual Retriggerable/Resettable Monostable Multivibrator | CD4528B | MC14528B | 4528 |
| CD4529B | Dual 4-Channel Analog Data Selector | - | MC14529B | - |
| CD4538B | Dual Monostable Multivibrator | - | MC14538 | - |
| CD4541B | Programmable Oscillator Timer | - | MC14541B | - |
| CD4543B | BCD-to-7-Segment Decoder (LCD) | - | MC14543B | - |
| CD4584B | Hex Schmitt Trigger (marked as MM74C14N) | 40106B | MC14584B | 40014 |
| CD4723B | Dual 4-Bit Addressable Latch 8-Bit Addressable Latch | - | - | 4723 |
| CD4724B |  | CD4724B | - | 4724 |

## AID Converter Cross Reference Guide

| Product | Description | T.I. | Mostek |  |
| :---: | :---: | :---: | :---: | :---: |
| ADC0808CCN | 8-Bit A/D w/8-Channel Analog Mux | ADC0808CN | MK50808N |  |
| ADC0809CCN | 8-Bit A/D w/8-Channel Analog Mux | ADC0809CN | MK50809N |  |
| ADC0816CCN | 8-Bit A/D w/16-Channel Analog Mux | ADC0816CN | MK50816N |  |
| ADC0817CCN | 8-Bit A/D w/16-Channel Analog Mux | ADC0817CN | MK50817N |  |

National Semiconductor complies with the CMOS "B" Series specification as called out in JEDEC Standard No. 13A. All parts called out as " $B$ " are double buffered and will meet as a minimum the electrical parameters listed in table A. As agreed upon in the JEDEC Spec, products callout out as "UB" are not double buffered but meet table A specifications with the exception of $\mathrm{V}_{\mathrm{IL}}$ and $\mathrm{V}_{1 \mathrm{H}}$, which will be $20 \%$ and $80 \%$, respectively, of $\mathrm{V}_{\mathrm{DD}}$. The 54C/74C family meets or exceeds the "B"|"UB" specifications as given in table A but are not marked "B"|"UB".

Table A

|  | Parameter | Temp. Range | $\begin{array}{\|c} \mathrm{V}_{\mathrm{DD}} \\ (\mathrm{Vdc}) \\ \hline \end{array}$ | Conditions | Limits |  |  |  |  |  |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | TLow* |  | $+25^{\circ} \mathrm{C}$ |  |  | $\mathrm{THIGH}^{* *}$ |  |  |
|  |  |  |  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IDD | Quiescent Device Current GATES <br> BUFFERS, FLIP-FLOPS | Mil. | $\begin{array}{r} 5 \\ 10 \\ 15 \end{array}$ | $V_{1}=V_{S S}$ or $V_{D D}$ |  | $\begin{array}{\|c\|} \hline 0.25 \\ 0.5 \\ 1.0 \\ \hline \end{array}$ |  |  | $\begin{gathered} \hline 0.25 \\ 0.5 \\ 1.0 \end{gathered}$ |  | $\begin{aligned} & 7.5 \\ & 15 \\ & 30 \end{aligned}$ | $\mu$ Adc |
|  |  | Comm. | $\begin{array}{r} 5 \\ 10 \\ 15 \end{array}$ | All valid input combinations |  | $\begin{aligned} & 1.0 \\ & 2.0 \\ & 4.0 \\ & \hline \end{aligned}$ |  |  | $\begin{aligned} & 1.0 \\ & 2.0 \\ & 4.0 \\ & \hline \end{aligned}$ |  | $\begin{gathered} 7.5 \\ 15 \\ 30 \\ \hline \end{gathered}$ | $\mu \mathrm{Adc}$ |
|  |  | Mil. <br> Comm. | $\begin{array}{r} 5 \\ 10 \\ 15 \\ 5 \\ 10 \\ 15 \end{array}$ | $V_{1}=V_{S S} \text { or } V_{D D}$ <br> All valid input combinations |  | $\begin{aligned} & 1.0 \\ & 2.0 \\ & 4.0 \\ & 4.0 \\ & 8.0 \\ & 16 \end{aligned}$ |  |  | $\begin{aligned} & 1.0 \\ & 2.0 \\ & 4.0 \\ & 4.0 \\ & 8.0 \\ & 16 \end{aligned}$ |  | 30 60 120 30 60 120 | $\mu$ Adc <br> $\mu \mathrm{Adc}$ |
|  |  | Mil. <br> Comm. | $\begin{array}{r} 5 \\ 10 \\ 15 \\ 5 \\ 10 \\ 15 \end{array}$ | $V_{I}=V_{S S} \text { or } V_{D D}$ <br> All valid input combinations |  | $\begin{aligned} & 5.0 \\ & 10 \\ & 20 \\ & 20 \\ & 40 \\ & 80 \end{aligned}$ |  |  | $\begin{aligned} & 5.0 \\ & 10 \\ & 20 \\ & 20 \\ & 40 \\ & 80 \end{aligned}$ |  | $\begin{aligned} & 150 \\ & 300 \\ & 600 \\ & 150 \\ & 300 \\ & 600 \\ & \hline \end{aligned}$ | $\mu \mathrm{Adc}$ <br> $\mu \mathrm{Adc}$ |
| VOL | Low-Level Output Voltage | All | $\begin{array}{r} 5 \\ 10 \\ 15 \end{array}$ | $\begin{aligned} & V_{1}=V_{S S} \text { or } V_{D D} \\ & \left\|I_{\mathrm{O}}\right\|<1 \mu \mathrm{~A} \end{aligned}$ |  | $\begin{array}{r} 0.05 \\ 0.05 \\ -0.05 \end{array}$ |  |  | $\begin{aligned} & 0.05 \\ & 0.05 \\ & 0.05 \end{aligned}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \\ & 0.05 \end{aligned}$ | Vdc |
| VOH | High-Level Output Voltage | All | $\begin{array}{r} 5 \\ 10 \\ 15 \\ \hline \end{array}$ | $\begin{aligned} & V_{1}=V_{S S} \text { or } V_{D D} \\ & \left\|I_{O}\right\|<1 \mu A \end{aligned}$ | $\begin{gathered} 4.95 \\ 9.95 \\ 14.95 \end{gathered}$ |  | $\begin{gathered} \hline 4.95 \\ 9.95 \\ 14.95 \\ \hline \end{gathered}$ |  |  | $\begin{gathered} \hline 4.95 \\ 9.95 \\ 14.05 \\ \hline \end{gathered}$ |  | Vdc |
| VIL | Input Low Voltage | All | $\begin{array}{r} 5 \\ 10 \\ 15 \\ \hline \end{array}$ | $\begin{array}{\|l\|} \hline \mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V}, \\ \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V}, \quad\left\|\mathrm{I}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A} \\ \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V} \text { or } 13.5 \mathrm{~V},\left\|I_{\mathrm{O}}\right\|<1 \mu \mathrm{~A} \\ \hline \end{array}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \\ & \hline \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \\ & \hline \end{aligned}$ | Vdc |
| $\mathrm{V}_{\mathrm{IH}}$ | Input High Voltage | All | $\begin{array}{r} 5 \\ 10 \\ 15 \\ \hline \end{array}$ | $\begin{array}{\|l\|} \hline \mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V},\left\|\mathrm{I}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A} \\ \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V},\left\|I_{\mathrm{O}}\right\|<1 \mu \mathrm{~A} \\ \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V} \text { or } 13.5 \mathrm{~V},\left\|I_{\mathrm{O}}\right\|<1 \mu \mathrm{~A} \\ \hline \end{array}$ | $\begin{aligned} & 3.5 \\ & 7.0 \\ & 11 \\ & \hline \end{aligned}$ |  | $\begin{aligned} & 3.5 \\ & 7.0 \\ & 11 \\ & \hline \end{aligned}$ |  |  | $\begin{aligned} & 3.5 \\ & 7.0 \\ & 11 \\ & \hline \end{aligned}$ |  | Vdc |
| IoL | Output Low (Sink) Current | Mil. <br> Comm. | $\begin{array}{r} 5 \\ 10 \\ 15 \\ 5 \\ 10 \\ 15 \end{array}$ | $\begin{array}{ll} \mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}, & \mathrm{~V}_{1}=0 \mathrm{~V} \text { or } 5 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}, & \mathrm{~V}_{1}=0 \mathrm{~V} \text { or } 10 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}, & \mathrm{~V}_{\mathrm{I}}=0 \mathrm{~V} \text { or } 15 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}, & \mathrm{~V}_{\mathrm{I}}=0 \mathrm{~V} \text { or } 5 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}, & \mathrm{~V}_{1}=0 \mathrm{~V} \text { or } 10 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}, & \mathrm{~V}_{\mathrm{I}}=0 \mathrm{~V} \text { or } 15 \mathrm{~V} \end{array}$ | 0.64 <br> 1.6 <br> 4.2 <br> 0.52 <br> 1.3 <br> 3.6 |  | $\begin{array}{\|c\|} \hline 0.51 \\ 1.3 \\ 3.4 \\ 0.44 \\ 1.1 \\ 3.0 \\ \hline \end{array}$ |  |  | $\begin{gathered} \hline 0.36 \\ 0.9 \\ 2.4 \\ 0.36 \\ 0.9 \\ 2.4 \\ \hline \end{gathered}$ |  | mAdc <br> mAdc |
| IOH | Output High (Source) Current | Mil. <br> Comm. | $\begin{array}{r} 5 \\ 10 \\ 15 \\ 5 \\ 10 \\ 15 \\ \hline \end{array}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{O}}=4.6 \mathrm{~V}, \quad \mathrm{~V}_{1}=0 \mathrm{~V} \text { or } 5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=0 \mathrm{~V} \text { or } 10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}, \\ & \mathrm{~V}_{1}=0 \mathrm{~V} \text { or } 15 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}, \quad \mathrm{~V}_{1}=0 \mathrm{~V} \text { or } 5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=0 \mathrm{~V} \text { or } 10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}, \mathrm{~V}_{1}=0 \mathrm{~V} \text { or } 15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \hline-0.25 \\ & -0.62 \\ & -1.8 \\ & -0.2 \\ & -0.5 \\ & -1.4 \end{aligned}$ |  | $\begin{array}{\|c\|} \hline-0.2 \\ -0.5 \\ -1.5 \\ -0.16 \\ -0.4 \\ -1.2 \\ \hline \end{array}$ |  |  | $\begin{gathered} -0.14 \\ -0.35 \\ -1.1 \\ -0.12 \\ -0.3 \\ -1.0 \\ \hline \end{gathered}$ |  | mAdc <br> mAdc |
| 1 | Input Current | Mil. Comm. | $\begin{aligned} & 15 \\ & 15 \end{aligned}$ | $\begin{aligned} & \hline V_{1}=0 \mathrm{~V} \text { or } 15 \mathrm{~V} \\ & \mathrm{~V}_{1}=0 \mathrm{~V} \text { or } 15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & \pm 0.1 \\ & \pm 0.3 \end{aligned}$ |  |  | $\begin{aligned} & \pm 0.1 \\ & \pm 0.3 \end{aligned}$ |  | $\begin{aligned} & \pm 1.0 \\ & \pm 1.0 \end{aligned}$ | $\mu$ Adc $\mu$ Adc |
| $\mathrm{C}_{1}$ | Input <br> Capacitance per Unit Load | All | , - | Any Input |  |  |  |  | 7.5 |  |  | pF |

Note: For current flow the convention is positive for current flowing into the device and negative flowing out of the device.
${ }^{*} T_{\text {LOW }}=-55^{\circ} \mathrm{C}$ for Military Temp. Range device, $-40^{\circ} \mathrm{C}$ for Commercial Temp. Range device.
${ }^{*} \mathrm{~T}_{\mathrm{HIGH}}=+125^{\circ} \mathrm{C}$ for Military Temp. Range device, $+85^{\circ} \mathrm{C}$ for Commercial Temp. Range device.

## Section 1

## MM54CXX/MM74CXX Series Logic

MM54C00/MM74C00 Quad 2-Input NAND Gate MM54C02/MM74C02 Quad 2-Input NOR Gate MM54C04/MM74C04 Hex Inverter MM54C10/MM74C10 Triple 3-Input NAND Gate MM54C20/MM74C20 Dual 4-Input NAND Gate

## General Description

These logic gates employ complementary MOS (CMOS) to achieve wide power supply operating range, low power consumption, high noise immunity and symmetric controlied rise and fall times. With features such as this the 54C/74C logic family is close to ideal for use in digital systems. Function and pin out compatibility with series 54/74 devices minimizes design time for those designers already familiar with the standard 54/74 logic family.

All inputs aie protected from damage due to static discharge by diode clamps to $\mathrm{V}_{\mathrm{CC}}$ and GND.

Features

- Wide supply voltage range
- Guaranteed noise margin
- High noise immunity
$0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.)
- Low power consumption

10 nW/package (typ.)

- Low power
fan out of 2
TTL compatibility


## Connection Diagrams



MM54C10/MM74C10


MM54C20/MM74C20


Absolute Maximum Ratings

Voltage at Any Pin
Operating Temperature Range
54C
74C
Storage Temperature Range
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
Maximum $V_{C C}$ Voltage
Package Dissipation
Lead Temperature (Soldering, 10 seconds)
-0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 3.0 V to 15 V

18 V
500 mW
$300^{\circ} \mathrm{C}$

## DC Electrical Characteristics

Min/max limits apply across the guaranteed temperature range unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0' Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | 0.5 1.0 | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $I_{\text {IN(1) }}$ | Logical "1" Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $1 \mathrm{IN}(0)$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| ICC | Supply Current | $V_{C C}=15 \mathrm{~V}$ |  | 0.01 | 15 | $\mu \mathrm{A}$ |
| Low Power to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IN}(1)}$ | Logical "1" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{C C}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}-1.5 \\ & \mathrm{~V}_{\mathrm{CC}}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical "0" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{C C}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.4 \\ & 4.4 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| CMOS to Low Power |  |  |  |  |  |  |
| $\mathrm{V}_{\operatorname{IN}(1)}$ | Logical "1" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4.0 \\ & 4.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical "0" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.0 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{C C}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{C C}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| Output Drive (See 54CI74C Family Characteristics Data Sheet) (short circuit current) |  |  |  |  |  |  |
| IsOURCE | Output Source Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{\text {IN(0) }}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \end{aligned}$ | -1.75 |  |  | mA |
| Isource | Output Source Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, \mathrm{~V}_{\operatorname{IN}(0)}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \end{aligned}$ | -8.0 |  |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{I N(1)}=5.0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 1.75 |  |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\text {IN }(1)}=10 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 8.0 |  | . | mA |

## AC Electrical Characteristics

$T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| MM54C00/MM74C00, MM54C02/MM74C02, MM54C04/MM74C04 |  |  |  |  |  |  |
| $t_{p d 0}, t_{p d 1}$ | Propagation Delay Time to Logical "1" or "0" | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 30 \end{aligned}$ | $\begin{aligned} & 90 \\ & 60 \end{aligned}$ | ns ns |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | (Note 2) |  | 6.0 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 3) Per Gate or Inverter |  | 12 |  | pF |
| MM54C10/MM74C10 |  |  |  |  |  |  |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Time to Logical "1" or "0" | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 60 \\ & 35 \end{aligned}$ | $\begin{array}{r} 100 \\ 70 \end{array}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{CIN}_{\text {IN }}$ | Input Capacitance | , (Note 2) |  | 7.0 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 3) Per Gate |  | 18 |  | pF |
| MM54C20/MM74C20 |  |  |  |  |  |  |
| $t_{\text {pd0 }}, t_{\text {pd1 }}$ | Propagation Delay Time to Logical "1" or "0" | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | 70 40 | $\begin{array}{r} 115 \\ 80 \end{array}$ | ns ns |
| $\mathrm{CIN}_{\text {I }}$ | Input Capacitance | (Note 2) |  | 9 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 3) Per Gate |  | 30 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{P D}$ determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note - AN-90.

## Typical Performance Characteristics



## Typical Performance Characteristics (Cont'd)



Switching Time Waveforms and AC Test Circuits

## CMOS to CMOS



NOTE: DELAYS MEASURED WITH INPUT $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}} \leq \mathbf{2 0} \mathrm{ns}$.

## MM54C08/MM74C08 Quad 2-Input AND Gate

## General Description

Employing complementary MOS (CMOS) transistors to achieve wide power supply operating range, low power consumption and high noise margin, these gates provide basic functions used in the implementation of digital integrated circuit systems. The N and P-channel enhancement mode transistors provide a symmetrical circuit with output swing essentially equal to the supply voltage. No dc power other than that caused by leakage current is consumed during static condition. All inputs are protected from damage due to static discharge by diode clamps to $V_{C C}$ and GND.

## Features

- Wide supply voltage range
3.0 V to 15 V
- Guaranteed noise margin 1.0 V
- High noise immunity
$0.45 \mathrm{~V}_{\mathrm{Cc}}$ (typ.)
- Low power fan out of 2

TTL compatibility driving 74L

- Low power
consumption
$10 \mathrm{nW} /$ package (typ.)

MM54C08/MM74C08


## Truth Tables

MM54C08/MM74C08

| INPUTS |  | OUTPUT |
| :---: | :---: | :---: |
| A | B | Y |
| L | L | L |
| L | H | L |
| H | L | L |
| H | H | H |

$H=$ High Level L= Low Level

## Absolute Maximum Ratings (Note 1)

Voltage at Any Pin Operating Temperature Range

MM54C08, MM54C86
MM74C08, MM74C86
Storage Temperature Range
Package Dissipation
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
Absolute Maximum $V_{C C}$
Lead Temperature (Soldering, 10 seconds)
$-0.3 V$ to $V_{c c}+0.3 V$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
3.0 V to 15 V

18 V
$300^{\circ} \mathrm{C}$

## DC Electrical Characteristics

Min/max limits apply across the guaranteed temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IN}(1)}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, I_{\mathrm{O}}=-10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & V \\ & V \end{aligned}$ |
| V OUT(0) | Logical "0" Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \end{aligned}$ | : |  | 0.5 1.0 | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\operatorname{IN}(1)$ | Logical " 1 " Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $1 \mathrm{IN}(0)$ | Logical "0" Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{1 N}=0 \mathrm{~V}$ | $-1.0$ | -0.005 |  | $\mu \mathrm{A}$ |
| Icc | Supply Current | $V_{C C}=15 \mathrm{~V}$ |  | 0.01 | 15 | $\mu \mathrm{A}$ |
| CMOSILPTTL Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IN}(1)}$ | Logical "1" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}-1.5 \\ & \mathrm{~V}_{\mathrm{CC}}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {IN }(0)}$ | Logical " 0 " Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & V \\ & V \end{aligned}$ |
| V OUT(0) | Logical "0" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+360 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| Output Drive (See 54C/74C Family Characteristics Data Sheet) (short circuit current) |  |  |  |  |  |  |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | $-1.75$ | -3.3 |  | mA |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | $-8.0$ | 15 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{\text {OUT }}=V_{C C} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | 1.75 | 3.6 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=\mathrm{V}_{\mathrm{CC}} \\ & T_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 8.0 | - 16 |  | mA |

## AC Electrical Characteristics

(MM54C08/MM74C08) $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :--- | :--- | :--- | :--- | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd0}}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Time to | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  | 80 | 140 | ns |
| $\mathrm{C}_{\mathrm{IN}}$ | Logical "1" or " 0 " | Input Capacitance |  | 40 | 70 | ns |
| $\mathrm{C}_{\mathrm{PD}}$ | Power Dissipation Capacitance | (Note 2) |  | 5.0 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note - AN-90.

## Typical Performance Characteristics

Propagation Delay Time vs Load Capacitance MM54C08/MM74C08

$\mathrm{C}_{\mathrm{L}}$ - LOAD CAPACITANCE (pF)

## AC Test Circuits



NOTE: DELAYS MEASURED WITH INPUT $t_{r}, t_{f}=20$ ns

## Switching Time Waveforms



## MM54C14/MM74C14 Hex Schmitt Trigger

## General Description

The MM54C14/MM74C14 Hex Schmitt Trigger is a monolithic complementary MOS (CMOS) integrated circuit constructed with N and P-channel enhancement transistors. The positive and negative going threshold voltages, $\mathrm{V}_{\mathrm{T}+}$ and $\mathrm{V}_{\mathrm{T}_{-}}$, show low variation with respect to temperature (typ. $0.0005 \mathrm{~V} /{ }^{\circ} \mathrm{C}$ at $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ ), and hysteresis, $\mathrm{V}_{\mathrm{T}_{+}}-\mathrm{V}_{\mathrm{T}_{-}} \geqslant 0.2 \mathrm{~V}_{\mathrm{CC}}$ is guaranteed.

All inputs are protected from damage due to static discharge by diode clamps to $\mathrm{V}_{\mathrm{CC}}$ and GND.

Features

- Wide supply voltage range
3.0 V to 15 V
- High noise immunity
$0.70 \mathrm{~V}_{\mathrm{CC}}$ (typ.)
$0.4 \mathrm{~V}_{\mathrm{CC}}$ (typ.)
$0.2 \mathrm{~V}_{\mathrm{CC}}$ guaranteed
$0.4 \mathrm{~V}_{\mathrm{Cc}}$ typ.
$0.2 \mathrm{~V}_{\mathrm{Cc}}$ guaranteed


## Connection Diagram



## Absolute Maximum Ratings

Voltage at Any Pin
Operating Temperature Range
MM54C14
MM74C14
Storage Temperature Range
Package Dissipation
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
Absolute Maximum $V_{C C}$
Lead Temperature（Soldering， 10 seconds）
-0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW
3.0 V to 15 V

18 V
$300^{\circ} \mathrm{C}$

## DC Electrical Characteristics

Min／max limits apply across the guaranteed temperature range unless otherwise noted．

|  | Parameter | Conditions | Min． | Typ． | Max． | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{T}+}$ | Positive Going Threshold Voltage | $\begin{aligned} & V_{\mathrm{CC}}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \hline 3.0 \\ & 6.0 \\ & 9.0 \end{aligned}$ | $\begin{array}{r} 3.6 \\ 6.8 \\ 10.0 \end{array}$ | $\begin{array}{r} 4.3 \\ 8.6 \\ 12.9 \end{array}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{T-}$ | Negative Going Threshold Voltage | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 0.7 \\ & 1.4 \\ & 2.1 \end{aligned}$ | $\begin{aligned} & 1.4 \\ & 3.2 \\ & 5.0 \end{aligned}$ | 2.0 4.0 6.0 | $\begin{aligned} & V \\ & v \\ & v \end{aligned}$ |
| $\mathrm{V}_{\mathrm{T}_{+}-} \mathrm{V}_{\mathrm{T}_{-}}$ | Hysteresis | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 1.0 \\ & 2.0 \\ & 3.0 \end{aligned}$ | $\begin{aligned} & 2.2 \\ & 3.6 \\ & 5.0 \end{aligned}$ | 3.6 7.2 10.8 | $\begin{aligned} & v \\ & v \\ & v \end{aligned}$ |
| $\mathrm{V}_{\text {OUT（1）}}$ | Logical＂1＂Output Voltage | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{V}_{\text {OUT（0）}}$ | Logical＂0＂Output Voltage | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{I}_{\text {IN（1）}}$ | Logical＂1＂Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $1 \mathrm{IN}(0)$ | Logical＂0＂Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{I}}=0 \mathrm{~V}$ | －1．0 | －0．005 |  | $\mu \mathrm{A}$ |
| ICC | Supply Current | $\begin{aligned} & V_{C C}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V} / 15 \mathrm{~V} \\ & V_{\mathrm{CC}}=5 \mathrm{~V}, V_{I N}=2.5 \mathrm{~V} \text { (Note 4) } \\ & V_{\mathrm{CC}}=10 \mathrm{~V}, V_{I N}=5 \mathrm{~V} \text { (Note 4) } \\ & V_{\mathrm{CC}}=15 \mathrm{~V}, V_{I N}=7.5 \mathrm{~V} \text { (Note 4) } \end{aligned}$ |  | $\begin{gathered} 0.05 \\ 20 \\ 200 \\ 600 \end{gathered}$ | 15 | $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ |
| CMOSILPTTL Interface |  |  |  |  |  |  |
| $V_{\text {IN（1）}}$ | Logical＂1＂Input Voltage | $V_{C C}=5 \mathrm{~V}$ | 4.3 |  |  | V |
| $V_{\text {IN（0）}}$ | Logical＂0＂Input Voltage | $V_{C C}=5 \mathrm{~V}$ |  |  | 0.7 | V |
| $\mathrm{V}_{\text {OUT（1）}}$ | Logical＂1＂Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & V \\ & v \end{aligned}$ |
| $\mathrm{V}_{\text {OUT（0）}}$ | Logical＇0＂Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & V \\ & V \end{aligned}$ |

## Output Drive（See 54C／74C Family Characteristics Data Sheet）（short circuit current）

| ISOURCE | Output Source Current （P－Channel） | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | －1．75 | －3．3 | mA |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Isource | Output Source Current （P－Channel） | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | －8．0 | －15 | mA |
| $I_{\text {SINK }}$ | Output Sink Current （N－Channel） | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, V_{O U T}=V_{C C} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | 1.75 | 3.6 | mA |
| ISINK | Output Sink Current （N－Channel） | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 8.0 | 16 | mA |

## AC Electrical Characteristics

$T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ ，unless otherwise specified．

|  | Parameter | Conditions | Min． | Typ． | Max． | Units |
| :--- | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay from Input | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ |  | 220 | 400 | ns |
| $\mathrm{C}_{\mathrm{IN}}$ | Io Output | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ |  | 80 | 200 | ns |
| $\mathrm{C}_{P D}$ | Input Capacitance | Power Dissipation Capacitance | （Note 3）Per Gate |  | 5.0 |  |
| pF |  |  |  |  |  |  |

Note 1：＂Absolute Maximum Ratings＂are those values beyond which the safety of the device cannot be guaranteed．Except for＂Ope－ rating Temperature Range＂they are not meant to imply that the devices should be operated at these limits．The table of＂Electrical Characteristics＂provides conditions for actual device operation．

Note 2：Capacitance is guaranteed by periodic testing．
Note 3： $\mathrm{C}_{\text {PD }}$ determines the no load ac power consumption of any CMOS device．For complete explanation see 54C／74C Family Charac－ teristics application note－AN－90．

Note 4：Only one of the six inputs is at $1 / 2 \mathrm{~V}_{\mathrm{CC}}$ ，the others are either at $\mathrm{V}_{\mathrm{CC}}$ or GND．

## Typical Applications

## Low Power Oscillator



$$
\begin{aligned}
& t_{1} \approx R C \ln \frac{V_{T_{+}}}{V_{T_{-}}} \\
& t_{2} \approx R C \ln \frac{V_{C C}-V_{T-}}{V_{C C}-V_{T_{+}}} \\
& f \approx \frac{1}{R C \ln \frac{V_{T_{+}+}\left(V_{C C}-V_{T_{-}}\right)}{V_{T-}\left(V_{C C}-V_{T_{+}}\right)} \approx \frac{1}{1.7 R C}}
\end{aligned}
$$



Note：The equations assume $t_{1}+t_{2} \gg t_{p d 0}+t_{\text {pd }}$ ，

## Typical Performance Characteristics



Note：For more information on output drive characteristics，power dissipation，and propagation delays，see AN－90．

## MM54C30／MM74C30 8－Input NAND Gate

## General Description

The logic gate employs complementary MOS（CMOS）to achieve wide power supply operating range，low power consumption and high noise immunity．Function and pin out compatibility with series 54／74 devices mini－ mizes design time for those designers familiar with the standard 54／74 logic family．

All inputs are protected from damage due to static dis－ charge by diode clamps to $\mathrm{V}_{\mathrm{CC}}$ and GND．

## Features

| －Wide supply voltage range | 3.0 V to 15 V |
| :--- | ---: |
| －Guaranteed noise margin | 1.0 V |
| －High noise immunity | $0.45 \mathrm{~V}_{\mathrm{CC}}$（typ．） |
| Low power | fan out of 2 <br> driving 74 L |
| TTL compatibility |  |

Logic and Connection Diagrams


TOP VIEW

```
Absolute Maximum Ratings (Note 1)
```

Voltage at Any Pin
Operating Temperature Range
MM54C30
MM74C30
Storage Temperature Range
Package Dissipation
Operating $V_{C C}$ Range
Absolute Maximum $V_{C C}$
Lead Temperature (Soldering, 10 seconds)
$-0.3 V$ to $V_{c c}+0.3 V$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
3.0 V to 15 V

18 V
$300^{\circ} \mathrm{C}$

## DC Electrical Characteristics

Min/max limits apply across temperature range unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | CMOS to CMOS |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IN}(1)}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical " 0 " Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{\mathrm{O}}=+10 \mu \mathrm{~A} \\ & V_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $I_{\text {IN(1) }}$ | Logical "1" Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{1}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| I (10) | Logical " 0 " Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| ICC | Supply Current | $V_{C C}=15 \mathrm{~V}$ |  | 0.01 | 15 | $\mu \mathrm{A}$ |
|  | CMOS/LPTTL Interface |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{cc}}-1.5 \\ & \mathrm{~V}_{\mathrm{cc}}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & V \\ & V \end{aligned}$ |
| Vout(0) | Logical '0" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |

Output Drive (See 54C174C Family Characteristics Data Sheet) (short circuit current)

| Isource | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | -1.75 | -3.3 | mA |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | -8.0 | -15 | mA |
| ISINK | Output Sink Current ( N -Channel) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=\mathrm{V}_{\mathrm{CC}} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | 1.75 | 3.6 | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 8.0 | 16 | mA |

## AC Electrical Characteristics

$T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :--- | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Delay Time to | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  | 125 | 180 | ns |
|  | Logical "1" or "0"" |  |  | 55 | 90 | ns |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance | (Note 2) |  | 4.0 |  | pF |
| $\mathrm{C}_{\mathrm{PD}}$ | Power Dissipation Capacitance | (Note 3) Per Gate |  | 26 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note - AN-90.

## Typical Performance Characteristics

Propagation Delay Time vs Load Capacitance

$\mathrm{C}_{\mathrm{L}}$-LOAD CAPACITANCE ( pF )

## Switching Time Waveforms



NOTE: DELAYS MEASURED WITH INPUT $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{t}}=\mathbf{2 0} \mathrm{ns}$.

## AC Test Circuit



## MM54C32/MM74C32 Quad 2-Input OR Gate

## General Description

Employing complementary MOS (CMOS) transistors to achieve low power and high noise margin, these gates provide the basic functions used in the implementation of digital integrated circuit systems. The N and P-channel enhancement mode transistors provide a symmetrical circuit with output swings essentially equal to the supply voltage. This results in high noise immunity over a wide supply voltage range. No dc power other than that caused by leakage current is consumed during static conditions. All inputs are protected against static discharge damage.

## Features

| Wide supply voltage range | 3.0 V to 15 V |
| :--- | ---: |
| Guaranteed noise margin | 1.0 V |
| High noise immunity | $0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.) |
| Low power | fan out of 2 <br> driving 74L |
| TTL compatibility |  |

## Connection Diagram



Absolute Maximum Ratings (Note 1)

Voltage at Any Pin
Operating Temperature Range
MM54C32
MM74C32
Storage Temperature Range
$-0.3 V$ to $V_{C C}+0.3 V$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$

Package Dissipation
500 mW
Operating $\mathrm{V}_{\mathrm{Cc}}$ Range
3.0 V to 15 V

Absolute Maximum $V_{C c}$ 18 V Lead Temperature (Soldering, 10 seconds)
$300^{\circ} \mathrm{C}$

## DC Electrical Characteristics

Min/max limits apply across temperature range unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0' Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{I}_{\mathrm{IN}(1)}$ | Logical "1" Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {IN(0) }}$ | Logical " 0 " Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| $I_{\text {cc }}$ | Supply Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 0.05 | 15 | $\mu \mathrm{A}$ |
| CMOS/LPTTL Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage <br> MM54C32 <br> MM74C32 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & V_{C C^{-1}} .5 \\ & V_{C C^{-1}} .5 \end{aligned}$ | , |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical " 0 " Input Voltage MM54C32 <br> MM74C32 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $V_{\text {OUT(1) }}$ | Logical " 1 " Output Voltage MM54C32 <br> MM74C32 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical " 0 " Output Voltage MM54C32 <br> MM74C32 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{aligned}$ |  |  | 0.4 0.4 | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |

## Output Drive (See 54C/74C Family Characteristics Data Sheet) (short circuit current)

| Isource | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | -1.75 | -3.3 | mA |
| :---: | :---: | :---: | :---: | :---: | :---: |
| I SOURCE | Output Source Current (P-Channel) | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | -8.0 | -15 | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 1.75 | 3.6 | mA |
| IsINK | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 8.0 | 16 | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :--- | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Delay Time to | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  | 80 | 150 | ns |
|  | Logical "1" or "0" | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ | 35 | 70 | ns |  |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance | Any Input (Note 2) |  | 5 |  | pF |
| $\mathrm{C}_{\mathrm{PD}}$ | Power Dissipation Capacitance | Per Gate (Note 3) |  | 15 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{P D}$ determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note - AN-90.

## MM54C42/MM74C42 BCD-to-Decimal Decoder

## General Description

The MM54C42/MM74C42 one-of-ten decoder is a monolithic complementary MOS (CMOS) integrated circuit constructed with N - and P-channel enhancement transistors. This decoder produces a logical " 0 " at the output corresponding to a four bit binary input from zero to nine, and a logical " 1 " at the other outputs. For binary inputs from ten to fifteen all outputs are logical " 1 ".

| - High noise immunity | $0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.) |
| :--- | ---: |
| Low power | 50 nW (typ.) |
| Medium speed operation | 10 MHz (typ.) |
|  | with $10 \mathrm{~V} \mathrm{~V}_{\mathrm{CC}}$ |

## Applications

- Automotive
- Data terminals
- Instrumentation
- Medical electronics
- Alarm systems
- Industrial electronics
- Remote metering
- Computers

Schematic Diagram


Connection Diagram


Truth Table

| inPuts | UTPUTS |
| :---: | :---: |
| D C B A | 01234567 |
| 0000 | 0 1 1 1 1 1 1 1 1 |
| 000 | 100111111111 |
| 001.0 | 1110011111111 |
| 000111 | 1119001111911 |
| 0100 | 111110011111 |
| 010 | 111111011 |
| 11 | 11111110 |
| 011 | 11.1111110 |
| 00 | 111111110 |
| 00 | 111111111110 |
| 010 | 11111111111 |
| 011 | 1111111.111 |
| 100 | 1111119111111 |
| $\begin{array}{llll}1 & 1 & 0 & 1 \\ 1 & 1 & 1\end{array}$ | $\begin{array}{llllllllll}1 & 1 & 1 & 1 & 1 & 1 & 1 & 1 & 1 & 1 \\ 1 & 1 & 1 & 1 & 1 & 1 & 1 & 1 & 1\end{array}$ |
| 110 | 1111111111111 |
| 1111 | 11 |

# Absolute Maximum Ratings (Note 1) 

Voltage at Any Pin (Note 1)
Operating Temperature Range
MM54C42
MM74C42
Storage Temperature Range
-0.3 V to $\mathrm{V}_{\mathrm{cc}}+0.3 \mathrm{~V}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$

| Package Dissipation | 500 mW |
| :--- | ---: |
| Operating $\mathrm{V}_{\mathrm{CC}}$ Range | 3.0 V to 15 V |
| Absolute Maximum $\mathrm{V}_{\mathrm{CC}}$ | 18 V |
| Lead Temperature (Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ |

DC Electrical Characteristics Min./max. limits apply across temperature range unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | v |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical " 0 " Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | 1.5 2.0 | v |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | v |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | v |
| $\mathrm{IIN}_{(1)}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  |  | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {IN(0) }}$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 |  | 300 | $\mu \mathrm{A}$ |
| lcc | Supply Current | $\mathrm{V}_{C C}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| CMOSILPTTL Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}-1.5 \\ & \mathrm{~V}_{\mathrm{CC}}-1.5 \end{aligned}$ |  |  | v |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical " 0 " Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{cC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | v |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | v |
| $V_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{cC}}=4.5 \mathrm{~V}, \mathrm{I}_{0}=360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | v |
| Output Drive (See 54C/74C Family Characteristics Data Sheet) $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ (short circuit current) |  |  |  |  |  |  |
| Isource | Output Source Current | $\mathrm{V}_{\text {CC }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {IN(0) }}=0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V}$ | -1.75 |  |  | mA |
| Isource | Output Source Current | $\mathrm{V}_{\text {CC }}=10 \mathrm{~V}, \mathrm{~V}_{\text {IN(0) }}=0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V}$ | -8.0 |  |  | mA |
| $I_{\text {SINK }}$ | Output Sink Current | $\mathrm{V}_{C C}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {IN(1) }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=\mathrm{V}_{\text {CC }}$ | 1.75 |  |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\text {IN(1) }}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=\mathrm{V}_{\text {CC }}$ | 8.0 |  |  | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{PF}$, unless otherwise specified.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :--- | :--- | :--- | ---: | ---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Delay Time to | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  | 200 | 300 | ns |
|  | Logical "0" or "1" | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ |  | 90 | 140 | ns |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance | (See note 2) |  | 5 |  | pF |
| $\mathrm{C}_{\mathrm{PD}}$ | Power Dissipation Capacitance | (See note 3) |  | 50 | . | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note - AN-90.

## MM54C48/MM74C48 BCD-to-7 Segment Decoder

## General Description

The MM54C48/MM74C48 BCD-to-7 segment decoder is a monolithic complementary MOS (CMOS) integrated circuit constructed with N - and P -channel enhancement transistors. Seven NAND gates and one driver are connected in pairs to make binary-coded decimal (BCD) data and its complement available to the seven decoding AND-OR-INVERT gates. The remaining NAND gate and three input buffers provide test blanking input/rippleblanking output, and ripple-blanking inputs.

## Features

- Wide supply voltage range
3.0 V to 15 V
- Guaranteed noise margin 1.0 V
- High noise immunity
- Low power
$0.45 \mathrm{~V}_{\mathrm{Cc}}$ (typ.)
TTL compatibility
fan out of 2 driving 74L
- High current sourcing output (up to 50 mA )
- Ripple blanking for leading or trailing zeros (optional)
- Lamp test provision


## Connection Diagram



TOP VIEW


## Absolute Maximum Ratings (Note 1)

Voltage at Any Pin
Operating Temperature Range
MM54C48
MM74C48
Storage Temperature Range
Package Dissipation
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
Absolute Maximum $\mathrm{V}_{\mathrm{CC}}$
Lead Temperature (Soldering, 10 seconds)
-0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW
3.0 V to 15 V

18 V
$300^{\circ} \mathrm{C}$

## DC Electrical Characteristics

Min/max limits apply across temperature range unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{v} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical " 1 " Output Voltage (RB Output Only) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, I_{0}=-10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $\mathrm{V}_{\text {OUt(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $\mathrm{I}_{\text {(1) }}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=15.0 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{1 \times(0)}$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{cc}}$ | Supply Current | $\mathrm{V}_{C C}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| CMOS/LPTTL Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{C C}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & V_{c c}-1.5 \\ & v_{c C}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{v} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical "0" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage (RB Output Only) | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-50 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-50 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $\mathrm{V}_{\text {OUt(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{C C}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |


| Output Drive (See 54C/74C Family Characteristics Data Sheet) |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Isource | Output Source Current (P-Channel) (RB Output Only) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0.4 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0.5 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & \hline-0.80 \\ & -4.0 \end{aligned}$ | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & T_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 1.75 | 3.6 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 8.0 | 16 |  | mA |
|  | Output Source Current | $\mathrm{V}_{\text {CC }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=3.4$ | -20 | -50 |  | mA |
|  | (NPN Bipolar) | $\mathrm{V}_{\text {CC }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=3.0$ |  | -65 |  | mA |
|  |  | $\mathrm{V}_{\text {CC }}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=8.4$ | -20 | -50 |  | mA |
|  |  | $\mathrm{V}_{\text {CC }}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=8.0$ |  | -65 |  | mA |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note - AN-90.

AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay to a " 1 " or " 0 " on Segment Outputs from Data Inputs | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 450 \\ & 160 \end{aligned}$ | $\begin{array}{r} 1500 \\ 500 \end{array}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pdo }}$ | Propagation Delay to a " 0 " on Segment Outputs from RB Input | $\begin{aligned} & V_{c C}=5.0 \mathrm{~V} \\ & V_{c \mathrm{C}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 500 \\ & 180 \end{aligned}$ | $\begin{array}{r} 1600 \\ 550 \end{array}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd0 }}$ | Propagation Delay to a " 0 " on Segment Outputs from Blanking Input | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 350 \\ & 140 \end{aligned}$ | $\begin{array}{r} 1200 \\ 450 \end{array}$ | ns ns |
| $t_{\text {pd1 }}$ | Propagation Delay to a " 1 " on Segment Outputs from Lamp Test | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 450 \\ & 160 \end{aligned}$ | $\begin{array}{r} 1500 \\ 500 \end{array}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {pd1 }}$ | Propagation Delay to a " 1 " on RB Output from RB Input | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 600 \\ & 250 \end{aligned}$ | $\begin{array}{r} 2000 \\ 800 \end{array}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd0 }}$ | Propagation Delay to a " 0 " on RB Output from RB Input | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} 140 \\ 50 \end{array}$ | $\begin{aligned} & 450 \\ & 150 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |

## Typical Applications

Typical Connection Utilizing the Ripple-Blanking Feature
Blanking Input Connection Diagram
 stage will not blank zeros)

(When RBO/BI is forced low, all segment outputs are off regardless of the state of any other input condition)

Light Emitting Diode (LED) Readout


**A filament pre-warm resistor is recommended to reduce filament thermal shock and increase the effective cold resistance of the filament.


Liquid Crystal (LC) Readout


Direct dc drive of LC's not recommended for life of LC readouts.

Truth Table

| DECIMAL OR | INPUTS |  |  |  |  |  | BI/RBO ${ }^{+}$ | OUTPUTS |  |  |  |  |  |  | NOTE |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| FUNCTION | LT | RBI | D | C | B | A |  | a | b | c | d | e | f | g |  |
| 0 | H | H | L | L | L | L | H | H | H | H | H | H | H | L | 1 |
| 1 | H | X | $L$ | L | L | H | H | L | H | H | L | L | L | L | 1 |
| 2 | H | X | L | L | H | L | H | H | H | L | H | H | L | H |  |
| 3 | H | X | L | L | H | H | H | H | H | H | H | 'L | L | H |  |
| 4 | H | x | L | H | L | L | H | L | H | H | L | L | H | H |  |
| 5 | H | $x$ | L | H | L | H | H | H | L | H | H | L | H | H |  |
| 6 | H | X | L | H | H | L | H | L | L | H | H | H | H | H |  |
| 7 | H | x | L | H | H | H | H | H | H | H | L | L | L | L |  |
| 8 | H | X | H | L | L | L | H | H | H | H | H | H | H | H |  |
| 9 | H | x | H | L | L | H | H | H | H | H | L | L | H | H |  |
| 10 | H | x | H | L | H | L | H | L | L | L | H | H | L | H |  |
| 11 | H | x | H | L | H | H | H | L | L | H | H | L | L | H |  |
| 12 | H | $x$ | H | H | L | $L$ | H | L | H | L | L | L | H | H |  |
| 13 | H | $x$ | H | H | L | H | H | H | L | L | H | L | H | H |  |
| 14 | H | x | H | H | H | L | H | L | L | L | H | H | H | H |  |
| 15 | H | x | H | H |  | H | H | L. | L | L | L | L | L | L |  |
| BI | $\times$ | X | X | x | $\times$ | X | L | L | L | L | L | L | L | L | 2 |
| RBI | H | L. | L | $L$ | L | L | L | L | L | L | L | L | L | L | 3 |
| LT | L | X | X | X | X | X | H | H | H | H | H | H | H | H | 4 |

$H=$ high level, $L=$ low level, $X=$ irrelevant
Note 1: The blanking input (BI) must be open when output functions $0-15$ are desired. The ripple-blanking input (RBI) must be high, if blanking of a decimal zero is not desired.
Note 2: When a low logic level is applied directly to the blanking input (BI), all segment outputs are low regardless of the level of any other input. Note 3: When ripple-blanking input (RBI) and inputs A, B, C, and D are at a low level with the lamp-test input high, all segment outputs go low and the ripple-blanking output (RBO) goes to a low level (response condition).
Note 4: When the blanking input/ripple-blanking output (BI/RBO) is open and a low is applied to the lamp-test input, all segment outputs are high. $\dagger$ One BI/RBO is wire-AND logic serving as blanking input (BI) and/or ripple-blanking output (RBO).

## MM54C73/MM74C73/MM54C76/MM74C76/MM54C107 MM74C107 Dual J-K Flip-Flops with Clear and Preset

## General Description

These dual J-K flip-flops are monolithic complementary MOS (CMOS) integrated circuits constructed with N -and P-channel enhancement transistors. Each flip-flop has independent J, K, clock and clear inputs and Q and Q outputs. The MM54C76/MM74C76 flip flops also include preset inputs and are supplied in 16 pin packages. These flip-flops are edge sensitive to the clock input and change state on the negative going transition of the clock pulses. Clear or preset is independent of the clock and is accomplished by a low level on the respective input.

## Features

- Supply voltage range
$3 V$ to 15 V
- Tenth power TTL compatible

$0.45 \mathrm{~V}_{\mathrm{Cc}}$ (typ.)
50 nW (typ.)
10 MHz (typ.) with 10 V supply


## Applications

| - Automotive | ■ Alarm systems |
| :--- | :--- |
| - Data terminals | ■ Industrial electronics |
| - Instrumentation | ■ Remote metering |
| - Medical electronics | ■ Computers |

## Logic and Connection Diagrams



MM54C73/MM74C73 and MM54C107/MM74C107



Note: A logic " 0 " on clear sets $\mathbf{0}$ to logic " 0 ."
MM54C73/MM74C73


Note: A logic " 0 " on clear sets 0 to logic " 0 ." MM54C107/MM74C107


Note 1: A logic " 0 " on clear sets $\mathbf{Q}$ to a logic " 0 . ' Note 2: A logic " 0 " on preset sets $\mathbf{0}$ to a logic " 1 ." MM54C76/MM74C76

## Absolute Maximum Ratings

Voltage at Any Pin (Note 1)
Operating Temperature Range
MM54CXX
MM74CXX
$-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
Storage Temperature $\quad-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
Package Dissipation
Lead Temperature (Soldering, 10 seconds)
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
500 mW
$300^{\circ} \mathrm{C}$
+3 V to 15 V

DC Electrical Characteristics Min/max limits apply across temperature range unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | V |
| $\mathrm{V}_{\text {IN }(0)}$ | Logical " 0 " Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | 1.5 2.0 | V |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | V |
| $V_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | 0.5 1.0 | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{I}_{\mathrm{N}(1)}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=15.0 \mathrm{~V}$ |  |  | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{IN}(0)}$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15.0 \mathrm{~V}$ | -1.0 |  |  | $\mu \mathrm{A}$ |
| $I_{C C}$ | Supply Current | $\mathrm{V}_{C C}=15.0 \mathrm{~V}$ |  | 0.050 | 60 | $\mu \mathrm{A}$ |

Low Power TTL to CMOS Interface

| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\mathrm{V}_{\mathrm{CC}}-1.5$ |  | V |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {IN }(0)}$ | Logical "0" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  | 0.8 | V |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ | 2.4 |  | V |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{aligned}$ |  | 0.4 | V |

Output Drive (See 54C/74C Family Characteristics Data Sheet) (short circuit current)

| Isource | Output Source Current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {IN(0) }}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \end{aligned}$ | $-1.75$ |  | mA |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Isource | Output Source Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{1 N(0)}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, V_{O U T}=0 \mathrm{~V} \end{aligned}$ | -8.0 |  | mA |
| ISINK | Output Sink Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{I N(1)}=5.0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 1.75 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, \mathrm{~V}_{I N(1)}=10 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 8.0 |  | mA |

AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance | Any Input |  | 5 |  | pF |
| $t_{p d}, t_{p d 1}$ | Propagation Delay Time to a Logical " 0 " or Logical " 1 " from Clock to Q or Q | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | 180 70 | $\begin{aligned} & 300 \\ & 110 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd0 }}$ | Propagation Delay Time to a Logical " 0 " from Preset or Clear | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} 200 \\ 80 \end{array}$ | $\begin{aligned} & 300 \\ & 130 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {pd }}$ | Propagation Delay Time to a Logical " 1 " from Preset or Clear | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} 200 \\ 80 \end{array}$ | $\begin{aligned} & 300 \\ & 130 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{s}$ | Time Prior to Clock Pulse that Data must be Present | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} 110 \\ 45 \end{array}$ | $\begin{array}{r} 175 \\ 70 \end{array}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {H }}$ | Time after Clock Pulse that J and K must be Held | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & -40 \\ & -20 \end{aligned}$ | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {PW }}$ | Minimum Clock Pulse Width $t_{W L}=t_{W H}$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} 120 \\ 50 \end{array}$ | $\begin{array}{r} 190 \\ 80 \end{array}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {PW }}$ | Minimum Preset and Clear Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 90 \\ & 40 \end{aligned}$ | $\begin{array}{r} 130 \\ 60 \end{array}$ | ns ns |
| $\mathrm{f}_{\text {MAX }}$ | Maximum Toggle Frequency | $\begin{aligned} & V_{c C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 2.5 \\ & 7.0 \end{aligned}$ | $\begin{array}{r} 4.0 \\ 11.0 \end{array}$ |  | MHz <br> MHz |
| $t_{r}, t_{f}$ | Clock Pulse Rise and Fall Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{array}{r} 15 \\ 5 \end{array}$ | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \end{aligned}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note - AN-90.

## AC Test Circuit



## Truth Table

| $t_{n}$ |  | $t_{n+1}$ |
| :---: | :---: | :---: |
| $J$ | $K$ | $\mathbf{Q}$ |
| 0 | 0 | $Q_{n}$ |
| 0 | 1 | 0 |
| 1 | 0 | 1 |
| 1 | 1 | $\bar{Q}_{n}$ |

$t_{\mathrm{n}}=$ bit time before clock pulse. $t_{n+1}=$ bit time after clock pulse.

| Preset | Clear | $\mathrm{O}_{\mathrm{n}}$ | $\overline{\mathrm{Q}}_{\mathrm{n}}$ |
| :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | 0 |
| 0 | 1 | 1 | 0 |
| 1 | 0 | 0 | 1 |
| 1 | 1 | ${ }^{*} \mathrm{Q}_{\mathrm{n}}$ | ${ }^{*} \overline{\mathrm{Q}}_{\mathrm{n}}$ |

* No change in output from
previous state.

Ripple Binary Counters


## 74C Compatibility



Guaranteed Noise Margin as a Function of VCC


## Switching Time Waveforms



## MM54C74/MM74C74 Dual D Flip-Flop

## General Description

The MM54C74/MM74C74 dual D flip flop is a monolithic complementary MOS (CMOS) integrated circuit constructed with N - and P-channel enhancement transistors. Each flip flop has independent data, preset, clear and clock inputs and Q and $\overline{\mathrm{Q}}$ outputs. The logic level present at the data input is transferred to the output during the positive going transition of the clock pulse. Preset or clear is independent of the clock and accomplished by a low level at the preset or clear input.

## Features

- Supply voltage range

3 V to 15 V

- Tenth power TTL compatible drive $2 \mathrm{LPT}^{2} \mathrm{~L}$ loads
- High noise immunity
- Low power
- Medium speed operation
$0.45 \mathrm{~V}_{\mathrm{cc}}$ (typ)
50 nW (typ)
10 MHz (typ)
with 10 V supply


## Applications

- Automotive
- Data terminals
- Instrumentation
- Medical electronics
- Alarm system
- Industrial electronics
- Remote metering
- Computers


## Logic and Connection Diagrams



Truth Table

| Preset | Clear | $\mathrm{Q}_{\mathrm{n}}$ | $\overline{\mathrm{Q}}_{\mathrm{n}}$ |
| :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | 0 |
| 0 | 1 | 1 | 0 |
| 1 | 0 | 0 | 1 |
| 1 | 1 | ${ }^{*} \mathrm{Q}_{\mathrm{n}}$ | ${ }^{*} \overline{\mathrm{Q}}_{\mathrm{n}}$ |

[^0]

Note: A logic " 0 " on clear sets $\mathbf{Q}$ to logic " 0 ." A logic " 0 " on preset sets $\mathbf{Q}$ to logic " 1 ."

Absolute Maximum Ratings
Voltage at Any Pin（Note 1）

$$
-0.3 \mathrm{~V} \text { to } \mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}
$$

Operating Temperature Range

## MM54C74

$-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
Storage Temperature
$-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ 500 mW
Package Dissipation
$\begin{array}{lr}\text { Lead Temperature（Soldering，} 10 \text { seconds）} \\ \text { Operating } V_{\text {CC }} \text { Range } & 300^{\circ} \mathrm{C} \\ +3 \mathrm{~V} \text { to }+15 \mathrm{~V}\end{array}$

## DC Electrical Characteristics

Min／max limits apply across temperature range unless otherwise specified．

|  | Parameter | Conditions | Min． | Typ． | Max． | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN（1）}}$ | Logical＂1＂Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\text {IN（0）}}$ | Logical＂0＂Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $V_{\text {OUT（1）}}$ | Logical＂1＂Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{cc}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $\mathrm{V}_{\text {OUT（0）}}$ | Logical＂0＂Output Voltage | $\begin{aligned} & V_{c C}=5.0 \mathrm{~V} \\ & V_{\mathrm{cC}}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $\mathrm{I}_{\mathbf{N}(1)}$ | Logical＂ 1 ＂Input Current | $\mathrm{V}_{\mathrm{CC}}=15.0 \mathrm{~V}$ |  |  | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {IN（0）}}$ | Logical＂0＂Input Current | $\mathrm{V}_{C C}=15.0 \mathrm{~V}$ | －1．0 |  |  | $\mu \mathrm{A}$ |
| ICC | Supply Current | $\mathrm{V}_{\mathrm{CC}}=15.0 \mathrm{~V}$ |  | 0.05 | 60 | $\mu \mathrm{A}$ |
| Low Power TTL／CMOS Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN（1）}}$ | Logical＂ 1 ＂Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\mathrm{V}_{\mathrm{CC}}-1.5$ |  |  |  |
| $\mathrm{V}_{\text {IN（0）}}$ | Logical＂0＂Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | 0.8 | V |
| $\mathrm{V}_{\text {OUT（1）}}$ | Logical＂1＂Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=-360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=-360 \mu \mathrm{~A} \end{aligned}$ | 2.4 |  |  | v |
| $V_{\text {OUT（0）}}$ | Logical＂0＂Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=360 \mu \mathrm{~A} \end{aligned}$ |  |  | 0.4 | v |
| Output Drive（See 54C／74C Family Characteristics Data Sheet） |  |  |  |  |  |  |
| Isource | Output Source Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{I N(0)}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \end{aligned}$ | －1．75 |  |  | mA |
| Isource | Output Source Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(0)}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \end{aligned}$ | －8．0 |  |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{I N(1)}=5.0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, V_{O U T}=V_{C C} \end{aligned}$ | 1.75 |  |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(1)}=10 \mathrm{~V} \\ & T_{A}=25^{\circ}, V_{O U T}=V_{C C} \end{aligned}$ | 8.0 |  |  | mA |

AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ ，unless otherwise noted．

|  | Parameter | Conditions | Min． | Typ． | Max． | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Any Input（See Note 2） |  | 5.0 |  | pF |
| $t_{p d}$ | Propagation Delay Time to a Logical＂ 0 ＂$t_{p d 0}$ or Logical＂ 1 ＂ $t_{\text {pd1 }}$ from Clock to Q or Q | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | 180 70 | $\begin{aligned} & 300 \\ & 110 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd }}$ | Propagation Delay Time to a Logical＂0＂from Preset or Clear | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | 180 70 | $\begin{aligned} & 300 \\ & 110 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd }}$ | Propagation Delay Time to a Logical＂1＂from Preset or Clear | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | 250 100 | $\begin{aligned} & 400 \\ & 150 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{s 0}, t_{s 1}$ | Time Prior to Clock Pulse that Data must be Present $t_{\text {SETUP }}$ | $\begin{aligned} & V_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 100 \\ 40 \end{gathered}$ | 50 |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{H 0}, t_{H 1}$ | Time after Clock Pulse that Data must be Held | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & -20 \\ & -8.0 \end{aligned}$ | 0 0 | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {PW1 }}$ | Minimum Clock Pulse Width $\left(t_{W L}=t_{W H}\right)$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | 100 40 | $\begin{aligned} & 250 \\ & 100 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {PW2 }}$ | Minimum Preset and Clear Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} 100 \\ 40 \end{array}$ | $\begin{array}{r} 160 \\ 70 \end{array}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{r}, t_{f}$ | Maximum Clock Rise and Fall Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{array}{r} 15.0 \\ 5.0 \end{array}$ |  |  | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \end{aligned}$ |
| $f_{\text {MAX }}$ | Maximum Clock Frequency | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 2.0 \\ & 5.0 \end{aligned}$ | 3.5 8.0 |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | See Note 3 |  | 40 |  | pF |

Note 1：＂Absolute Maximum Ratings＂are those values beyond which the safety of the device cannot be guaranteed．Except for＂Ope－ rating Temperature Range＂they are not meant to imply that the devices should be operated at these limits．The table of＂Electrical Characteristics＂provides conditions for actual device operation．
Note 2：Capacitance is guaranteed by periodic testing．
Note 3： $\mathrm{C}_{\text {PD }}$ determines the no load ac power consumption of any CMOS device．For complete explanation see 54C／74C Family Charac－ teristics application note－AN－90．

## Switching Time Waveforms



## AC Test Circuit



## Typical Applications

Ripple Counter（Divide by $2^{\text {n }}$ ）


Shift Register



Guaranteed Noise Margin as a Function of $V_{C C}$


## MM54C83/MM74C83 4-Bit Binary Full Adder

## General Description

The MM54C83/MM74C83 4-bit binary full adder performs the addition of two 4-bit binary numbers. A carry input $\left(\mathrm{C}_{0}\right)$ is included and the sum ( $\Sigma$ ) outputs are provided for each bit and the resultant carry $\mathrm{C}_{4}$ ) is obtained from the fourth bit. Since the carry-ripple-time is the limiting delay in the addition of a long word length, carry look-ahead circuitry has been included in the design to minimize this delay. Also, the logic levels of the input and output, including the carry, are in their true form. Thus the end-around carry is accomplished without the need for level inversion.

## Features

- Wide supply voltage range 3 V to 15 V
- Guaranteed noise margin
- High noise immunity
- Low power TTL compatibility
- Fast carry ripple
( $\mathrm{C}_{0}$ to $\mathrm{C}_{4}$ )
- Fast summing
( $\Sigma_{\text {IN }}$ to $\Sigma_{\text {OUT }}$ )
$0.45 \mathrm{~V}_{\mathrm{Cc}}$ (typ.)
fan out of 2
driving 74L
50 ns (typ.) @ $V_{C C}=10 \mathrm{~V}$ and $C_{L}=50 \mathrm{pF}$
125 ns (typ.)@ $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ and $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$

Logic Diagram

## Absolute Maximum Ratings (Note 1)

| Voltage at Any Pin | -0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$ |
| :--- | ---: |
| Operating Temperature Range |  |
| MM54C83 | $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| MM74C83 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Package Dissipation | 500 mW |
| Operating $\mathrm{V}_{\mathrm{CC}}$ Range | 3 V to 15 V |
| Absolute Maximum $\mathrm{V}_{\mathrm{CC}}$ | 18 V |
| Lead Temperature (Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ |

DC Electrical Characteristics Min/max limits apply across temperature range unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | V |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical " 0 " Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{\mathrm{O}}=+10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, I_{\mathrm{O}}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{I}_{\text {IN(1) }}$ | Logical "1" Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{N}(0)}$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| ICC | Supply Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| CMOSILPTTL Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\operatorname{IN}(1)}$ | Logical "1" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}-1.5 \\ & \mathrm{~V}_{\mathrm{CC}}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | V |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical " 0 " Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{C C}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Output Drive (See 54C/74C Family Characteristics Data Sheet) (short circuit current) |  |  |  |  |  |  |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | -1.75 | -3.3 |  | mA |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \\ & T_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | -8.0 | -15 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 1.75 | 3.6 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 8.0 | 16 |  | mA |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note - AN-90.

AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay from $\mathrm{C}_{0}$ to $\mathrm{C}_{4}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{cc}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{cc}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} 120 \\ 50 \end{array}$ | $\begin{array}{r} 200 \\ 80 \end{array}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{pd1}}$ | Propagation Delay from Sum Inputs to $\mathrm{C}_{4}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | 250 90 | $\begin{aligned} & 450 \\ & 150 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay from $\mathrm{C}_{0}$ to Sum Outputs | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 350 \\ & 125 \end{aligned}$ | $\begin{aligned} & 550 \\ & 200 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay from Sum Inputs to Sum Outputs | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} 300 \\ 90 \end{array}$ | $\begin{aligned} & 550 \\ & 150 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{Cl}_{\text {IN }}$ | Input Capacitance | Any Input (Note 2) |  | 5.0 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | Per Package (Note 3) |  | 120 |  | pF |

## Connection Diagram



Switching Time Waveforms


Inputs must be thed to appropriate logic level.

## Truth Table

(

[^1]Note: Input conditions at A3, A2, B2 and C0 are used to determine outputs $\Sigma 1$ and $\Sigma 2$ and the value of the internal carry $C 2$. The values at $C 2, A 3, B 3, A 4$, and $B 4$ are then used to determine outputs $\Sigma 3, \Sigma 4$, and C 4 .

## Typical Applications

## APPLICATION

Connect the MM54C83/MM74C83 in the following manner to implement a dual single bit full adder.

## CASCADING

Connect the MM54C83/MM74C83 in the following manner to implement full adders with more than 4 bits.


## MM54C85／MM74C85 4－Bit Magnitude Comparator

## General Description

The MM54C85／MM74C85 is a four－bit magnitude compa－ rator which will perform comparison of straight binary or BCD codes．The circuit consists of eight comparing Inputs（A0，A1，A2，A3，B0，B1，B2，B3），three cascading Inputs（ $A>B, A<B$ and $A=B$ ），and three outputs（ $A>B$ ， $A<B$ and $A=B$ ）．This device compares two four－bit words（ $A$ and $B$ ）and determines whether they are ＂greater than，＂＂less than，＂or＂equal to＂each other by a high level on the appropriate output．For words greater than four－bits，units can be cascaded by connecting the outputs（ $A>B, A<B$ ，and $A=B$ ）of the least significant stage to the cascade inputs（ $A>B, A<B$ and $A=B$ ）of the next－significant stage．In addition the least signifi－ cant stage must have a high level voltage（ $\mathrm{V}_{\text {IN（1）}}$ ）applied to the $\mathrm{A}=\mathrm{B}$ input and low level voltages $\left(\mathrm{V}_{\mathrm{IN}(0)}\right)$ applied to $A>B$ and $A<B$ inputs．

## Features

Wide supply voltage range 3.0 V to 15 V
－Guaranteed noise margin 1．0V
－High noise immunity $\quad 0.45 \mathrm{~V}_{\mathrm{CC}}$（typ．）
－Low power fan out of 2
TTL compatibility

## Logic Diagrams



Absolute Maximum Ratings (Note 1)
$\begin{array}{lr}\text { Voltage at Any Pin } & -0.3 \mathrm{~V} \text { to } \\ \text { Operating Temperature Range } & -55^{\circ} \mathrm{C} \\ \text { MM54C85 } & -40^{\circ} \mathrm{C} \\ \text { MM74C85 } & -65^{\circ} \mathrm{C} \\ \text { Storage Temperature Range } & \\ \text { DC Electrical Characteristics }\end{array}$
$V_{C C}+0.3 V$

$$
\begin{gathered}
-55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \\
-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \\
-65^{\circ} \mathrm{C} \text { to }+150^{\circ} \mathrm{C}
\end{gathered}
$$

| Package Dissipation | 500 mW |
| :--- | ---: |
| Operating $\mathrm{V}_{\mathrm{CC}}$ Range | 3.0 V to 15 V |
| $\mathrm{~V}_{\mathrm{CC}}$ | 18 V |
| Lead Temperature (Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ |

DC Electrical Characteristics Min./max. limits apply across temperature range unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | v |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | V |
| $\mathrm{V}_{\text {Out(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $1 \mathrm{IN}(1)$ | Logical "1" Input Current | $\mathrm{V}_{\text {CC }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {IN(0) }}$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{Cc}}$ | Supply Current | $V_{C C}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| CMOSILPTTL Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{VCC}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & V_{C C}-1.5 \\ & V_{C C}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \hline \mathrm{V} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical " 0 " Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | v |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical " 1 " Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | v |
| $\mathrm{V}_{\text {OUt(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & v \\ & v \end{aligned}$ |

Output Drive (See 54C/74C Family Characteristics Data Sheet) (short circuit current)

| Isource | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | -1.75 | -3.3 | mA |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | -8.0 | -15 | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 1.75 | 3.6 | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current ( N -Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 8.0 | 16 | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{p d}$ | Propagation Delay from any A or B Data Input to any Data Output | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 250 \\ & 100 \end{aligned}$ | $\begin{aligned} & 600 \\ & 300 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd }}$ | Propagation Delay Time from any Cascade Input to any Output | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 200 \\ & , 100 \end{aligned}$ | $\begin{aligned} & 500 \\ & 250 \end{aligned}$ | ns ns |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Any Input |  | 5.0 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 3) Per Package |  | 45. |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note - AN-90.

Typical Applications
rour Digit Comparator


Connection Diagram


## Switching Time Waveforms



Unused inputs must be tied to an appropriate logic level.

## Truth Table

| COMPARING INPUTS |  |  |  | CASCADING INPUTS |  |  | OUTPUTS |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| A3, B3 | A2, B2 | A1, B1 | AO, BO | A $>$ B | $A<B$ | $A=B$ | $A>B$ | A<B | $A=B$ |
| $\mathrm{A} 3>\mathrm{B} 3$ | $x$ | $x$ | X | $x$ | $x$ | $x$ | H | L | L |
| A3< B3 | x | x | x | X | X | x | L | H | L |
| $A 3=B 3$ | A2 $>$ B2 | x | $\times$ | $x$ | $x$ | $x$ | H | L | L |
| $A 3=B 3$ | A2 < B2 | x | x | $x$ | $x$ | X | L | H | L |
| $A 3=B 3$ | $A 2=B 2$ | A1 > B1 | X | X | x | X | H | L | L |
| $A 3=B 3$ | $A 2=B 2$ | A1 < B1 | x | $x$ | $x$ | x | L | H | L |
| $A 3=B 3$ | $A 2=B 2$ | $A_{1} 1=B 1$ | $\mathrm{A} 0>\mathrm{BO}$ | x | x | X | H | L | L |
| $A 3=B 3$ | $A 2=B 2$ | $A 1=B 1$ | $A 0<B 0$ | x | x | x | L | H | L |
| $A 3=B 3$ | $\mathrm{A} 2=\mathrm{B} 2$ | $A 1=B 1$ | $A 0=B 0$ | H | L | L | H | L | L |
| $A 3=B 3$ | $A 2=B 2$ | $A 1=B 1$ | $A 0=B 0$ | L | H | $L$ | L | H | L |
| A3 $=$ B3 | - $\mathrm{A} 2=\mathrm{B} 2$ | $A 1=B 1$ | $A 0=B 0$ | ᄂ | L | H | L | L | H |
| $\mathrm{A} 3=\mathrm{B} 3$ | $\mathrm{A} 2=\mathrm{B} 2$ | $A 1=B 1$ | $A 0=B 0$ | L | H | H | L | H | H |
| $A 3=B 3$ | $\mathrm{A} 2=\mathrm{B} 2$ | $A 1=B 1$ | $A 0=B 0$ | H | L | H | H | L | H |
| $A 3=B 3$ | $\mathrm{A} 2=\mathrm{B} 2$ | $A 1=B 1$ | $A 0=B 0$ | H | H | H | H | H | H |
| A3 $=$ B3 | $\mathrm{A} 2=\mathrm{B} 2$ | $A 1=B 1$ | $A 0=B 0$ | H | H | L | H | H | L |
| $\mathrm{A} 3=\mathrm{B} 3$ | $\mathrm{A} 2=\mathrm{B} 2$ | $A 1=B 1$ | $A 0=B 0$ | L | L | L | L | L | L |

## MM54C86／MM74C86 Quad 2－Input EXCLUSIVE－OR Gate

## General Description

Employing complementary MOS（CMOS）transistors to achieve wide power supply operating range，low power consumption and high noise margin these gates pro－ vide basic functions used in the implementation of digi－ tal integrated circuit systems．The N and P－channel enhancement mode transistors provide a symmetrical circuit with output swing essentially equal to the supply voltage．No dc power other than that caused by leakage current is consumed during static condition．All inputs are protected from damage due to static discharge by diode clamps to $\mathrm{V}_{\mathrm{CC}}$ and GND．

## Features

－Wide supply voltage range 3.0 V to 15 V
－Guaranteed noise margin
－High noise immunity $0.45 \mathrm{~V}_{\mathrm{CC}}$（typ．）

Low power
TTL compatibility
－Low power consumption
－The MM54C86／MM74C86 follows the MM54LS86／MM74LS86 Pinout．

## Connection Diagram



## Truth Table

MM54C08／MM74C08

| INPUTS |  | OUTPUT |
| :---: | :---: | :---: |
| A | B | $\mathbf{Y}$ |
| L | L | L |
| L | $H$ | $H$ |
| $H$ | L | $H$ |
| $H$ | $H$ | L |

$$
H=\text { High Level } L=\text { Low Level }
$$

## Absolute Maximum Ratings

Voltage at Any Pin (Note 1)
Operating Temperature Range MM54C86 MM74C86
Storage Temperature Range
Package Dissipation
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
Absolute Maximum $\mathrm{V}_{\mathrm{Cc}}$
Lead Temperature (Soldering, 10 seconds)

$$
-0.3 \mathrm{~V} \text { to } \mathrm{V}_{\mathrm{Cc}}+0.3 \mathrm{~V}
$$

$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW
3.0 V to 15 V

## DC Electrical Characteristics

Min/max limits apply across temperature range unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | CMOS to CMOS |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | V |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \text { V } \\ & \mathrm{V} \end{aligned}$ |
| Vout(0) | Logical " 0 " Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | 0.5 1.0 | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\operatorname{liN(1)}$ | Logical "1" Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| IN(0) | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| Icc | Supply Current | $V_{C C}=15 \mathrm{~V}$ |  | 0.01 | 15 | $\mu \mathrm{A}$ |
|  | CMOS/LPTTL Interface |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}-1.5 \\ & \mathrm{~V}_{\mathrm{CC}}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{v} \\ & \mathrm{v} \end{aligned}$ |
| $V_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| Vout(0) | Logical '0.' Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+360 \mu \mathrm{~A} \end{aligned}$ | . |  | $\begin{aligned} & 0.4 \\ & 0.4 \\ & \hline \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Output Drive (See 54C/74C Family Characteristics Data Sheet) (short circuit current) |  |  |  |  |  |  |
| Isource | Output Source Current (P.Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | -1.75 | -3.3 |  | mA |
| ISOURCE | Output Source Current (P-Channel) | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{\text {OUT }}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | -8.0 | -15 |  | mA |
| Isink | Output Sink Current (N-Channel) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=\mathrm{V}_{\mathrm{CC}} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | 1.75 | 3.6 |  | mA |
| $I_{\text {SINK }}$ | Output Sink Current ( N -Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 8.0 | 16 |  | mA |

## AC Electrical Characteristics

(MM54C86/MM74C86) $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

|  | Parameter | Conditions | Min. | Typ. | Max. |
| :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Time to Logical | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  |  |  |
|  | "1" or "0" | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ |  | 110 | 185 |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance | Note 2 | 50 | 90 | ns |
| $\mathrm{C}_{\mathrm{PD}}$ | Power Dissipation Capacitance | (Note 3) Per Gate |  | 5.0 |  |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note - AN-90.

## Typical Performance Characteristics

Propagation Delay Time vs Load Capacitance MM54C86/MM74C86


## AC Test Circuits



NOTE: DELAYS MEASURED WITH INPUT $t_{r}, t_{t}=20 \mathrm{~ns}$

## Switching Time Waveforms



## General Description

The MM54C89/MM74C89 is a 16-word by 4-bit random access read/write memory. Inputs to the memory consist of four address lines, four data input lines, a write enable line and a memory enable line. The four binary address inputs are decoded internally to select each of the 16 possible word locations. An internal address register, latches the address information on the positive to negative transition of the memory enable input. The four TRI-STATE ${ }^{\circledR}$ data output lines working in conjunction with the memory enable input provides for easy memory expansion.
Address Operation: Address inputs must be stable $t_{S A}$ prior to the positive to negative transition of memory enable. It is thus not necessary to hold address information stable for more than $t_{H A}$ after the memory is enabled (positive to negative transition of memory enable).

Note: The timing is different that the DM7489 in that a positive to negative transition of the memory enable must occur for the memory to be selected.

Write Operation: Information present at the data inputs is written into the memory at the selected address by bringing write enable and memory enable low.

Read Operation: The complement of the information which was written into the memory is non-destructively read out at the four outputs. This is accomplished by selecting the desired address and bringing memory enable low and write enable high.

When the device is writing or disabled the output assumes a TRI-STATE (Hi-z) condition.

## Features

| - Wide supply voltage range | 3.0 V to 15 V |
| :--- | ---: |
| - Guaranteed noise margin | 1.0 V |
| - High noise immunity | $0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.) |
| fan out of 2 |  |
| - Low power | driving 74 L |
| TTL compatibility | $100 \mathrm{nW} /$ package (typ.) |
| - Low power consumption | 130 ns (typ.) at $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ |

- TRI-STATE output

MM54C90/MM74C90 4-Bit Decade Counter MM54C93/MM74C93 4-Bit Binary Counter

## General Description

The MM54C90/MM74C90 decade counter and the MM54C93/MM74C93 binary counter and complementary MOS (CMOS) integrated circuits constructed with N and P-channel enhancement mode transistors. The 4-bit decade counter can reset to zero or preset to nine by applying appropriate logic level on the $R_{01}, R_{02}, R_{91}$ and $\mathrm{R}_{92}$ inputs. Also, a separate flip-flop on the A-bit enables the user to operate it as a divide-by-2,5 or 10 frequency counter. The 4-bit binary counter can be reset to zero by applying high logic level on inputs $R_{01}$ and $R_{02}$, and a separate flip-flop on the A-bit enables the user to operate it as a divide-by-2, -8 , or -16 divider. Counting occurs on the negative going edge of the input pulse.

All inputs are protected against static discharge damage.

## Features

- Wide supply voltage range

3 V to 15 V

- Guaranteed noise margin
- High noise immunity
- Low power

TTL compatibility

- The MM54C93/MM74C93 follows the $0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.)
fan out of 2 driving 74L MM54L93/MM74L93 Pinout


## Logic and Connection Diagrams




top view

Absolute Maximum Ratings

Voltage at Any Pin (Note 1) Operating Temperature Range MM54C90, MM54C93
MM74C90, MM74C93
Package Dissipation
$-0.3 V$ to $V_{C C}+0.3 V$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

500 mW

Operating $V_{C C}$ Range
3 V to 15 V
Absolute Maximum $\mathrm{V}_{\mathrm{CC}}$
18 V
Storage Temperature Range $\quad-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
Lead Temperature (Soldering, 10 seconds) $300^{\circ} \mathrm{C}$

DC Electrical Characteristics Min./max. limits apply across temperature range unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | CMOS to CMOS |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{gathered} 1.5 \\ 2 \end{gathered}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{\mathrm{O}}=-10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, I_{\mathrm{O}}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9 \end{aligned}$ |  |  | V |
| Vout(0) | Logical "0" Output Voltage | $\begin{aligned} & V_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | 0.5 1 | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\operatorname{liN(1)}$ | Logical "1" Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1 | $\mu \mathrm{A}$ |
| $1 \mathrm{IN}(0)$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V}$ | -1 | -0.005 |  | $\mu \mathrm{A}$ |
| ICC | Supply Current | $\mathrm{V}_{C C}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
|  | CMOS/LPTTL Interface |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage MM54C90, MM54C93 MM74C90, MM74C93 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & V_{C C}-1.5 \\ & V_{C C}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical " 0 "' Input Voltage MM54C90, MM54C93 MM74C90, MM74C93 | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \\ & V_{C C}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical " 1 " Output Voltage MM54C90, MM54C93 MM74C90, MM74C93 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical "0" Output Voltage MM54C90, MM54C93 MM74C90, MM74C93 | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V}, I_{O}=360 \mu \mathrm{~A} \\ & V_{C C}=4.75 \mathrm{~V}, I_{O}=360 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Output Drive (See 54C/74C Family Characteristics Data Sheet) (short circuit current) |  |  |  |  |  |  |
| ISOURCE | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | -1.75 | -3.3 |  | mA |
| ISOURCE | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | -8 | -15 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 1.75 | 3.6 |  | mA |
| Isink | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 8 | 16 |  | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {pd0 }}, t_{\text {pd } 1}$ | Propagation Delay Time from $A_{I N}$ to $Q_{A}$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} 200 \\ 80 \end{array}$ | $\begin{aligned} & 400 \\ & 150 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd0 }}, t_{\text {pd } 1}$ | Propagation Delay Time from $A_{\text {IN }}$ to $Q_{B}$ (MM54C93/MM74C93) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 450 \\ & 160 \end{aligned}$ | $\begin{aligned} & 850 \\ & 300 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {pd0 }}, t_{\text {pd } 1}$ | Propagation Delay Time from $\mathrm{A}_{\text {IN }}$ to $\mathrm{Q}_{\mathrm{B}}$ (MM54C90/MM74C90) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 450 \\ & 160 \end{aligned}$ | $\begin{aligned} & 800 \\ & 300 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |

AC Electrical Characteristics (Cont' d .) $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Time from AIN to $Q_{C}$ (MM54C93/MM74C93) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 500 \\ & 200 \end{aligned}$ | $\begin{array}{r} 1050 \\ 400 \end{array}$ | ns ns |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Time from $A_{\text {IN }}$ to $Q_{C}$ (MM54C90/MM74C90) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 500 \\ & 200 \end{aligned}$ | $\begin{array}{r} 1000 \\ 400 \end{array}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Time from $A_{I N}$ to $Q_{D}$ (MM54C93/MM74C93) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | 600 250 | $\begin{array}{r} 1200 \\ 500 \end{array}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Time from $A_{I N}$ to $Q_{D}$ (MM54C90/MM74C90) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 450 \\ & 160 \end{aligned}$ | $\begin{aligned} & 800 \\ & 300 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Time from $R_{01}$ or $R_{02}$ to $Q_{A}, Q_{B}, Q_{C}$ or $Q_{D}$ (MM54C93/MM74C93) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | 150 75 | $\begin{aligned} & 300 \\ & 150 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Time from $R_{01}$ or $R_{02}$ to $Q_{A}, Q_{B}, Q_{C}$ or $Q_{D}$ (MM54C90/MM74C90) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | 200 75 | $\begin{aligned} & 400 \\ & 150 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Time from $R_{91}$ or $R_{92}$ to $Q_{A}$ or $Q_{D}$ (MM54C90/MM74C90) | $\begin{aligned} & V_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 250 \\ & 100 \end{aligned}$ | $\begin{aligned} & 500 \\ & 200 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {pw }}$ | Min. $\mathrm{R}_{01}$ or $\mathrm{R}_{02}$ Pulse Width (MM54C93/MM74C93) | $\begin{aligned} & V_{c C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 600 \\ & 300 \end{aligned}$ | $\begin{aligned} & 250 \\ & 125 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pw }}$ | Min. $\mathrm{R}_{01}$ or $\mathrm{R}_{02}$ Pulse Width (MM54C90/MM74C90) | $\begin{aligned} & V_{c C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 600 \\ & 300 \end{aligned}$ | $\begin{aligned} & 250 \\ & 125 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {PW }}$ | Min. R $\mathrm{R}_{91}$ or R $\mathrm{R}_{92}$ Pulse Width (MM54C90/MM74C90) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 500 \\ & 250 \end{aligned}$ | $\begin{aligned} & 200 \\ & 100 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{r}, t_{f}$ | Maximum Clock Rise and Fall Time | $\begin{aligned} & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | 15 5 | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \end{aligned}$ |
| ${ }^{\text {w }}$ w | Minimum Clock Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 250 \\ & 100 \end{aligned}$ | 100 50 |  | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{f}_{\text {MAX }}$ | Maximum Clock Frequency | $\begin{aligned} & V_{c C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 2 \\ & 5 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance | Any Input (Note 2) |  | 5 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | Per Package (Note 3) |  | 45 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{P D}$ determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note - AN-90.

## AC Test Circuits



Clock rise and fall tume $t_{t}=t_{f}=20 \mathrm{~ns}$


MM54C93/MM74C93


Note 1. MM54C90, MM74C90 and MM54C93, MM74C93
are solid ine waveforms. Dashed line wave torms are for
Truth Tables

MM54C90/MM74C90 4-Bit Decade Counter BCD Count Sequence

| count | OUTPUT |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | $\mathbf{O}_{\mathrm{D}}$ | $\mathbf{Q}_{\mathrm{C}}$ | $\mathrm{Q}_{\mathrm{B}}$ | $\mathbf{Q}_{\mathbf{A}}$ |
| 0 | L | L | L | L |
| 1 | L | L | L | H |
| 2 | L | L | H | L |
| 3 | L | L | H | H |
| 4 | L | H | L | L |
| 5 | L | H | L | H |
| 6 | L | H | H | L |
| 7 | L | H | H | H |
| 8 | H | L | L | L |
| 9 | H | L | L | H |

Output $\mathrm{Q}_{\mathrm{A}}$ is connected to input B for
BCD count.
$H=$ High level
L = Low level
X $=$ Irrelevant

Reset/Count Function Table

| RESET INPUTS |  |  |  | OUTPUT |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{R}_{01}$ | $\mathrm{R}_{02}$ | $\mathrm{R}_{91}$ | $\mathrm{R}_{92}$ | $\mathrm{O}_{\mathrm{D}}$ | $\mathrm{O}_{\mathrm{C}}$ |  | $\mathrm{O}_{\mathrm{A}}$ |
| H | H | L | X | L | L | L | L |
| H | H | X | L | L | L | L | L |
| X | X | H | H | H | L | L | H |
| X | L | X | L |  |  |  |  |
| L | X | L | X |  |  |  |  |
| L | X | X | L |  |  | NT |  |
| X | L | L | X |  |  |  |  |

MM54C93/MM74C93 4-Bit Binary Counter
Binary Count Sequence

| COUNT | OUTPUT |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | $\mathrm{Q}_{\mathrm{D}}$ | $\mathrm{Q}_{\mathrm{C}}$ | $\mathrm{O}_{\mathrm{B}}$ | $\mathrm{Q}_{\mathrm{A}}$ |
| 0 | L | L | L | L |
| 1 | L | L | L | H |
| 2 | L | L | H | L |
| 3 | L. | L | H | H |
| 4 | L | H | L | L |
| 5 | L | H | L | H |
| 6 | L | H | H | L |
| 7 | L | H | H | H |
| 8 | H | L | L | L |
| 9 | H | L | L | H |
| 10 | H | L | H | L |
| 11 | ${ }^{-}$ | L | H | H |
| 12 | H | H | L | L |
| 13 | H | H | L | H |
| 14 | H | H | H | L |
| 15 | H | H | H | H |

Output $Q_{A}$ is connected to input $B$ for binary count sequence.
$H$ = High level
L = Low level
X = Irrelevant

Reset/Count Function Table

| RESET INPUTS |  | OUTPUT |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $R_{01}$ | $R_{02}$ | $Q_{D}$ | $Q_{C}$ | $Q_{B}$ | $Q_{A}$ |  |
| $H$ | $H$ | $L$ | $L$ | $L$ | $L$ |  |
| $L$ | $X$ |  | COUNT |  |  |  |
| $X$ | $L$ |  | COUNT |  |  |  |

## MM54C95/MM74C95 4-Bit Right-Shift Left-Shift Register

## General Description

This 4-bit shift register is a monolithic complementary MOS (CMOS) integrated circuit composed of four D flip flops. This register will perform right-shift or left-shift operations dependent upon the logical input level to the mode control. A number of these registers may be connected in series to form an N -bit right-shift or left-shift register.
When a logical " 0 " level is applied to the mode control input, the output of each flip flop is coupled to the $D$ input of the succeeding flip flop. Right-shift operation is performed by clocking at the clock 1 input, and serial data entered at the serial input, clock 2 and parallel inputs A through D are inhibited. With a logical " 1 " level applied to the mode control, outputs to succeeding stages are decoupled and parallel loading is possible, or with external interconnection, shift-left operation can be accomplished by connecting the output of each flip flop to the parallel input of the previous flip flop and serial data is entered at input $D$.

## Features

Medium speed operation
High noise immunity

- Low power
- Tenth power TTL compatible
- Wide supply voltage range

10 MHz (typ.)
$\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$
$0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.)
$100 \mathrm{nW} /$ (typ.)
Drive 2 LTTL loads

- Synchronous parallel load
- Parallel inputs and outputs from each flip flop
- Negative edge triggered clocking
- The MM54C95/MM74C95 follows the MM54L95/MM74L95 Pinout.


## Applications

- Data terminals
- Alarm systems
- Instrumentation
- Automotive
- Medical electronics
- Industrial electronics
- Computers


## Block and Connection Diagrams




Mode control $=0$ for right shift
Mode control = 1 for left shift or parallel load

## Function Table

| INPUTS |  |  |  |  |  |  |  | OUTPUTS |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| MODE CONTROL | CLOCKS |  | SERIAL | PARALLEL |  |  |  | $\mathrm{a}_{\text {A }}$ | $\mathrm{O}_{\mathrm{B}}$ | $\mathrm{O}_{\mathrm{c}}$ | $O_{D}$ |
|  | 2 (L) | 1 (R) |  | A | B | c | D |  |  |  |  |
| H | H | $x$ | $x$ | x | x | x | X | $\mathrm{O}_{\text {AO }}$ | $\mathrm{O}_{\text {во }}$ | $\mathrm{O}_{\mathrm{co}}$ | $\mathrm{Q}_{\mathrm{DO}}$ |
| H | $\downarrow$ | $x$ | $\times$ | a | $b$ | c | d | a | b | c | d |
| H | $\downarrow$ | $\times$ | $x$ | $\mathrm{O}_{8}{ }^{+}$ | $\mathrm{a}_{\mathrm{c}}{ }^{\dagger}$ | $\mathrm{o}_{0}{ }^{\dagger}$ | d | $\mathrm{o}_{\mathrm{Bn}}$ | $\mathrm{o}_{\text {cn }}$ | $\mathrm{O}_{\mathrm{Dn}}$ | d |
| $L$ | L | H | x | x | x | x | x | $\mathrm{O}_{\text {AO }}$ | $\mathrm{O}_{\mathrm{BO}}$ | $\mathrm{O}_{\mathrm{co}}$ | $\mathrm{O}_{00}$ |
| L. | X | $\downarrow$ | H | $x$ | $x$ | X | X | H | $\mathrm{a}_{\text {An }}$ | $\mathrm{O}_{\mathrm{Bn}}$ | $Q_{\text {c }}$ |
| L | X | $\downarrow$ | L | $x$ | x | x | x | L | $\mathrm{a}_{\text {An }}$ | $\mathrm{O}_{\mathrm{Bn}}$ | $\mathrm{Q}_{\mathrm{cn}}$ |
| $\dagger$ | L | L | $x$ | $x$ | $x$ | x | x | $\mathrm{O}_{\text {AO }}$ | $\mathrm{Q}_{\mathrm{BO}}$ | $\mathrm{Q}_{\mathrm{co}}$ | $\mathrm{Q}_{\mathrm{DO}}$ |
| 1 | L | L. | $x$ | $x$ | x | x | x | $\mathrm{O}_{\text {AO }}$ | $\mathrm{Q}_{\mathrm{Bo}}$ | $\mathrm{a}_{\mathrm{co}}$ | $\mathrm{Q}_{00}$ |
| $\downarrow$ | L | H | $x$ | $x$ | x | X | x | $\mathrm{O}_{\text {AO }}$ | $\mathrm{O}_{80}$ | $\mathrm{O}_{\mathrm{co}}$ | $0_{00}$ |
| $\dagger$ | H | L | $x$ | $x$ | x | $x$ | $x$ | $\mathrm{O}_{\text {AO }}$ | $\mathrm{O}_{\mathrm{BO}}$ | $\mathrm{O}_{\mathrm{co}}$ | $\mathrm{a}_{0}$ |
| $\uparrow$ | H | H | X | $x$ | X | $x$ | X | $\mathrm{O}_{40}$ | $\mathrm{Q}_{\mathrm{Bo}}$ | $\mathrm{O}_{\mathrm{co}}$ | $\mathrm{O}_{\mathrm{D} 0}$ |
| $\dagger$ | L | H | x | $x$ | $x$ | $x$ | x | Unde |  |  |  |
| $\downarrow$ | H | L | x | x | x | x | x | Oper | 9 Con | ons |  |

[^2]Absolute Maximum Ratings (Note 1)

| Voltage at Any Pin | -0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$ |
| :--- | ---: |
| Operating Temperature | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM54C95 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| MM74C95 | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |

Maximum $V_{c c}$ Voltage
18 V
Package Dissipation 500 mW
Operating $\mathrm{V}_{\mathrm{CC}}$ Range $+3 V$ to $+15 V$
Lead Temperature (Soldering, 10 sec .) $300^{\circ} \mathrm{C}$

## DC Electrical Characteristics Max./min. limits apply across temperature range unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IN}(1)}$ | Logical "1" Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Vout ${ }^{\text {(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 4.5 \\ 9 \end{gathered}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Vout(0) | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{gathered} 0.5 \\ 1 \end{gathered}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{I}_{\mathbf{N}(1)}$ | Logical "1" Input Current | $\mathrm{V}_{C C}=15 \mathrm{~V}$ |  |  | 1 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {IN(0) }}$ | Logical "0" Input Current | $V_{C C}=15 \mathrm{~V}$ | -1 |  |  | $\mu \mathrm{A}$ |
| ICC | Supply Current | $V_{C C}=15 \mathrm{~V}$ |  | 0.050 | 300 | $\mu \mathrm{A}$ |
| Low Power TTL/CMOS Interface |  |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{array}{\|l\|} \hline V_{C C}-1.5 \\ V_{C C}-1.5 \end{array}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical '0" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \text { v } \\ & \text { V } \end{aligned}$ |
| VOUT(1) | Logical "1" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | V |
| VOUT(0) | Logical '0" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Output Drive (See 54C/74C Family Characteristics Data Sheet) |  |  |  |  |  |  |
| Isource | Output Source Current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{I N(0)}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \end{aligned}$ | -1.75 |  |  | mA |
| Isource | Output Source Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(0)}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, V_{O U T}=0 \mathrm{~V} \end{aligned}$ | -8.0 |  |  | mA |
| $I_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{I N(1)}=5.0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 1.75 |  |  | mA |
| Isink | Output Sink Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(1)}=10 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, V_{O U T}=V_{C C} \end{aligned}$ | 8.0 |  |  | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {pd }}$ | Propagation Delay Time to a Logical "0" or Logical "1" from Clock to Q or Q | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 200 \\ 80 \end{gathered}$ | $\begin{aligned} & 400 \\ & 160 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{s 0}, t_{s 1}$ | Time Prior to Clock Pulse that Data must be Preset | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{c C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 60 \\ & 25 \end{aligned}$ | $\begin{aligned} & 30 \\ & 10 \end{aligned}$ |  | ns <br> ns |
| $t_{H 0}, t_{\text {H }}$ | Time After Clock Pulse that Data must be Held | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{c c}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 25 \\ & 10 \end{aligned}$ | $\begin{aligned} & 10 \\ & 50 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {PW }}$ | Minimum Clock Pulse Width ( $\mathrm{t}_{\mathrm{WL}}=\mathrm{t}_{\mathrm{WH}}$ ) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 100 \\ 50 \end{gathered}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {SM }}$ | Time Prior to Clock Pulse that Mode Control must be Preset | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 200 \\ & 100 \end{aligned}$ | $\begin{aligned} & 100 \\ & 50 \end{aligned}$ |  | ns ns |
| $\mathrm{f}_{\text {MAX }}$ | Maximum Input Clock Frequency | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 3 \\ 6.5 \end{gathered}$ | $\begin{gathered} 5 \\ 10 \end{gathered}$ |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $\mathrm{ClN}_{\text {IN }}$ | Input Capacitance | Any Input. (Note 2) |  | 5 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 3) |  | 100 |  | pF |
| Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation. <br> Note 2: Capacitance is guaranteed by periodic testing. <br> Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C174C Family Characteristics application note AN-90. |  |  |  |  |  |  |

## MM54C150/MM74C150 16-Line to 1-Line Multiplexer MM72C19/MM82C19 TRI-STATE ${ }^{\circledR}$ 16-Line to 1-Line Multiplexer

## General Description

The MM54C150/MM74C150 and MM72C19/MM82C19 multiplex 16 digital lines to 1 output. A 4-bit address code determines the particular 1-of-16 inputs which is routed to the output. The data is inverted from input to output.

A strobe override places the output of MM54C150/ MM74C150 in the logical " 1 " state and the output of MM72C19/MM82C19 in the high-impedance state.

All inputs are protected from damage due to static discharge by diode clamps to $\mathrm{V}_{\mathrm{CC}}$ and GND.

## Features

| Wide supply voltage range | 3.0 V to 15 V |
| :--- | ---: |
| Guaranteed noise margin | 1.0 V |
| - High noise immunity | $0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.) |
| - TTL compatibility | Drive 1 TTL Load |

## Connection Diagram


MM54C150/MM74C150, MM72C19/MM82C19

Absolute Maximum Ratings
(Note 1)
Voltage at Any Pin
Operating Temperature Range
MM54C150, MM72C19
MM74C150, MM82C19
Storage Temperature Range
Package Dissipation
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
$V_{C C}$
Lead Temperature (Soldering, 10 sec.$)$
-0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$

$$
\begin{array}{r}
-55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \\
-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \\
-65^{\circ} \mathrm{C} \text { to }+150^{\circ} \mathrm{C} \\
500 \mathrm{~mW} \\
3.0 \mathrm{~V} \text { to } 15 \mathrm{~V} \\
18 \mathrm{~V} \\
300^{\circ} \mathrm{C}
\end{array}
$$

DC Electrical Characteristics Max./min. limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| V IN(0) | Logical "0" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | 1.5 2.0 | V |
| VOUT(1) | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, I_{\mathrm{O}}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {OUT }}(0)$ | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | 0.5 1.0 | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{I}_{\mathrm{IN}(1)}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {IN(0) }}$ | Logical "0" Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| loz | Output Current in High Impedance State MM73C19/MM82C19 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=15 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0 \mathrm{~V} \end{aligned}$ | $-1.0$ | $\begin{array}{r} 0.005 \\ -0.005 \end{array}$ | 1.0 | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |
| ICC | Supply Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| TTL Interiace |  |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{array}{ll} \hline 54 \mathrm{C}, 72 \mathrm{C} & V_{\mathrm{CC}}=4.5 \mathrm{~V} \\ 74 \mathrm{C}, 82 \mathrm{C} & V_{\mathrm{CC}}=4.75 \mathrm{~V} \end{array}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}-1.5 \\ & \mathrm{~V}_{\mathrm{CC}}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{array}{ll} 54 \mathrm{C}, 72 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ 74 \mathrm{C}, 82 \mathrm{C} & V_{\mathrm{CC}}=4.75 \mathrm{~V} \end{array}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {OUT }}$ (1) | Logical "1" Output Voltage | $\begin{array}{ll} 54 \mathrm{C}, 72 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-1.6 \mathrm{~mA} \\ 74 \mathrm{C}, 82 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-1.6 \mathrm{~mA} \end{array}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | V |
| Vout(0) | Logical "0" Output Voltage | $\begin{array}{ll} 54 \mathrm{C}, 72 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=1.6 \mathrm{~mA} \\ 74 \mathrm{C}, 82 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=1.6 \mathrm{~mA} \\ \hline \end{array}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \\ & \hline \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Output Drive (Short Circult Current) |  |  |  |  |  |  |
| Isource | Output Source Current (P-Channel) | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | -4.35 | -8 |  | mA |
| $I_{\text {SOURCE }}$ | Output Source Current (P-Channel) | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | -20 | -40 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\mathrm{V}_{C C}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=\mathrm{V}_{C C}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | 4.35 | 8 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $V_{C C}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=\mathrm{V}_{C C}, T_{A}=25^{\circ} \mathrm{C}$ | 20 | 40 |  | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Time to a | $\mathrm{V}_{\mathrm{cc}}=5.0 \mathrm{~V}$ |  | 250 | 600 | ns |
|  | Logical "0" or Logical "1" | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ |  | 110 | 300 | ns |
|  | from Data Inputs to Output | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF}$ |  | 290 | 650 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF}$ |  | 120 | 330 | ns |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Time to a | $\mathrm{V}_{\mathrm{cC}}=5.0 \mathrm{~V}$ |  | 290 | 650 | ns |
|  | Logical "0" or Logical " 1 " from Data Select Inputs to Output | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ |  | 120 | 330 | ns |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Time to a | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  | 120 | 300 | ns |
|  | Logical "0" or Logical " 1 " from Strobe to Output MM54C150/MM74C150 | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ |  | 55 | 150 | ns |
| $\mathrm{t}_{1 \mathrm{H}}, \mathrm{t}_{\mathrm{OH}}$ | Delay from Strobe to High | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}$ |  | 80 | 200 | ns |
|  | Impedance State MM72C19/MM82C19 | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}$ |  | 60 | 150 | ns |
| $t_{\text {H1 }}, \mathrm{t}_{\mathrm{H} 0}$ | Delay from Strobe to Logical | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}$ |  | 80 | 250 | ns |
|  | "1" Level or to Logical "0" | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}$ |  | 30 | 120 | ns |
|  | Level (from High Impedance State) <br> MM72C19/MM82C19 |  |  |  |  |  |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Any Input, (Note 2) |  | 5.0 |  | pF |
| $\mathrm{Cout}^{\text {O }}$ | Output Capacitance MM72C19/MM82C19 | (Note 2) |  | 11.0 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 3) |  | 100 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics.' provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note AN-90.

| D | c | B | A | STROBE | E0 | E1 | E2 | E3 | E4 | INPUTS |  |  |  |  |  |  |  |  |  |  | $\frac{\text { OUTPUT }}{w}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |  |  |  | E5 | E6 | E7 | E8 | E9 | E10 | E11 | E12 | $E 13$ | E14 | E15 |  |
| x | x | x | x | 1 | $\times$ | $x$ | $x$ | X | x | $x$ | x | $x$ | $x$ | $x$ | $\cdot \mathrm{x}$ | $x$ | $x$ | $x$ | x | $x$ | 1 * |
| 0 | 0 | 0 | 0 | 0 | 0 | $x$ | $x$ | x | x | $x$ | x | $x$ | $x$ | x | $\times$ | x | x | x | x | $x$ | 1 |
| 0 | 0 | 0 | 0 | 0 | 1 | $\times$ | $x$ | $x$ | x | $x$ | x | $x$ | $x$ | $\times$ | x | x | $x$ | $x$ | x | $x$ | 0 |
| 0 | 0 | 0 | 1 | 0 | $x$ | 0 | $\times$ | $x$ | x | $\times$ | x | $x$ | $x$ | $\times$ | $x$ | $x$ | $x$ | x | x | $x$ | 1 |
| 0 | 0 | 0 | 1 | 0 | x | 1 | $\times$ | $x$ | x | x | x | $x$ | x | x | x | x | x | x | x | $x$ | 0 |
| 0 | 0 | 1 | 0 | 0 | $x$ | $x$ | 0 | $x$ | $\times$ | x | x | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | x | $x$ | 1 |
| 0 | 0 | 1 | 0 | 0 | $x$ | $x$ | 1 | x | $\times$ | x | $x$ | $x$ | $x$ | $\times$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | 0 |
| 0 | 0 | 1 | 1 | 0 | X | x | x | 0 | $x$ | $x$ | $x$ | X | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | X | $x$ | 1 |
| 0 | 0 | 1 | 1 | 0 | $x$ | $x$ | $x$ | 1 | $\times$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | 0 |
| 0 | 1 | 0 | 0 | 0 | $x$ | $x$ | x | x | 0 | x | x | $x$ | x | $\times$ | x | x | $x$ | x | x | x | 1 |
| 0 | 1 | 0 | 0 | 0 | $x$ | $x$ | $x$ | $\times$ | 1 | x | $x$ | $x$ | $x$ | $x$ | x | x | $x$ | $x$ | x | $x$ | 0 |
| 0 | 1 | 0 | 1 | 0 | $x$ | $x$ | $x$ | x | x | 0 | x | $x$ | x | $x$ | x | $x$ | $x$ | $x$ | x | $x$ | 1 |
| 0 | 1 | 0 | 1 | 0 | x | $x$ | $x$ | $x$ | x | 1 | x | $x$ | $x$ | $x$ | x | x | $x$ | $x$ | X | $x$ | 0 |
| 0 | 1 | 1 | 0 | 0 | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | 0 | x | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | 1 |
| 0 | 1 | 1 | 0 | 0 | $x$ | $x$ | x | $\times$ | x | x | 1 | x | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | 0 |
| 0 | 1 | 1 | 1 | 0 | $x$ | $x$ | x | $\times$ | $x$ | $x$ | $x$ | 0 | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | 1 |
| 0 | 1 | 1 | 1 | 0 | $x$ | $x$ | $x$ | $x$ | $x$ | x | x | 1 | x | $\times$ | x | x | $x$ | x | $x$ | $x$ | 0 |
| 1 | 0 | 0 | 0 | 0 | x | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | 0 | x | x | $x$ | $x$ | $x$ | x | $x$ | 1 |
| 1 | 0 | 0 | 0 | 0 | x | x | $x$ | $x$ | $x$ | $x$ | $x$ | x | 1 | x | $x$ | $x$ | x | $x$ | $x$ | $x$ | 0 |
| 1 | 0 | 0 | 1 | 0 | x | x | x | $x$ | x | $x$ | $x$ | x | $x$ | 0 | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | 1 |
| 1 | 0 | 0 | 1 | 0 | x | x | x | x | $x$ | $x$ | $x$ | $x$ | $x$ | 1 | $\times$ | $x$ | X | $x$ | $x$ | $x$ | 0 |
| 1 | 0 | 1 | 0 | 0 | $\times$ | x | $\times$ | x | $x$ | $x$ | x | $\times$ | $x$ | x | 0 | $\times$ | $x$ | $x$ | $x$ | $x$ | 1 |
| 1 | 0 | 1 | 0 | 0 | $x$ | $x$ | $x$ | $x$ | $x$ | x | x | x | $x$ | x | 1 | $\times$ | $x$ | $x$ | $x$ | $x$ | 0 |
| 1 | 0 | 1 | 1 | 0 | x | x | x | x | $x$ | $x$ | $x$ | x | $x$ | x | $x$ | 0 | $x$ | $x$ | $x$ | $x$ | 1 |
| 1 | 0 | 1 | 1 | 0 | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | 1 | $x$ | $x$ | $x$ | $x$ | 0 |
| 1 | 1 | 0 | 0 | 0 | x | $x$ | x | $x$ | x | x | x | x | x | x | x | $x$ | 0 | $x$ | x | $x$ | 1 |
| 1 | 1 | 0 | 0 | 0 | x | $x$ | $x$ | $x$ | $x$ | $x$ | x | $x$ | $\cdots x$ | x | x | $x$ | 1 | $\times$ | x | x | 0 |
| 1 | 1 | 0 | 1 | 0 | x | x | x | x | x | x | $\times$ | x | $x$ | x | x | $\times$ | $x$ | 0 | x | ' $x$ | 1 |
| 1 | 1 | 0 | 1 | 0 | $\times$ | x | x | x | X | X | X | X | $x$ | x | x | x | x | 1 | x | x | 0 |
| 1 | 1 | 1 | 0 | 0 | x | x | x | $x$ | x | x | x | $x$ | $\times$ | x | x | x | x | x | 0 | x | 1 |
| 1 | 1 | 1 | 0 | 0 | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | x | x | 1 | $x$ | 0 |
| 1 | 1 | 1 | 1 | 0 | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | $x$ | x | $x$ | $x$ | $x$ | x | x | x | 0 | 1 |
| 1 | 1 | 1 | 1 | 0 | x | x | $x$ | $x$ | x | x | x | $\times$ | $\times$ | x | $\times$ | x | x | x | x | 1 | 0 |

*For MM72C19/MM82C19 this would be Hi-Z, everything else is the same.




Note: Delays measured with input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}} \leq \mathbf{2 0} \mathrm{ns}$.

${ }^{\mathrm{t}} \mathrm{HO}$



MM72C19/MM82C19


## MM54C151/MM74C151 8-Channel Digital Multiplexer

## General Description

The MM54C151/MM74C151 multiplexer is a monolithic complementary MOS (CMOS) integrated circuit constructed with N - and P-channel enhancement transistors.

This data selector/multiplexer contains on-chip binary decoding. Two outputs provide true (output Y) and complement (output W) data. A logical " 1 " on the strobe input forces $W$ to a logical " 1 " and $Y$ to a logical " 0 ".

All inputs are protected against electrostatic effects.

## Features

- Supply voltage range

3 V to 15 V

- Tenth power TTL compatible
- High noise immunity drive 2 LPTTL loads
- Low power
$.45 \mathrm{~V}_{\mathrm{cc}}$ (typ.)
50 nW (typ.)


## Applications

| $\square$ Automotive | $■$ Alarm systems |
| :--- | :--- |
| $\square$ Data terminals | $■$ Industrial electronics |
| $\square$ Instrumentation | $\square$ Remote metering |
| $\square$ Medical electronics | $\square$ Computers. |

## Logic and Connection Diagrams

Automotive
Data terminals

- Instrumentation
Medical electronics
- Industrial electronics
- Remote metering
Computers.


| Absolute Maximum Ratings | (Note 1$)$ |
| :--- | ---: |
| Voltage at Any Pin | -0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$ |
| Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM54C151 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| MM74C151 | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Storage Temperature Range | 18 V |
| Maximum $V_{\mathrm{CC}}$ Voltage | 500 mW |
| Package Dissipation | 3 V to 15 V |
| Operating V V Range | $300^{\circ} \mathrm{C}$ |

DC Electrical Characteristics Max./min. limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{1 \times(1)}$ | Logical "1" Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{gathered} \hline 3.5 \\ 8 \end{gathered}$ |  |  | $\begin{aligned} & \mathrm{v} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{gathered} 1.5 \\ 2 \end{gathered}$ | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{\mathrm{O}}=-10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $V_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & \mathrm{V}_{C C}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $\mathrm{I}_{\mathbf{N ( 1 )}}$ | Logical " 1 " Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  |  | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{1 \times(0)}$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 |  |  | $\mu \mathrm{A}$ |
| ICC | Supply Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| CMOS to LPTTTL Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\operatorname{IN}(1)}$ | Logical " 1 " Input Voltage | $\begin{array}{ll} \hline 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{array}$ | $\begin{aligned} & V_{c c}-1.5 \\ & V_{c c}-1.5 \end{aligned}$ |  |  | $\begin{gathered} \mathrm{V} \\ \mathrm{~mA} \end{gathered}$ |
| $\mathrm{V}_{1 \times(0)}$ | Logical "0" Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{array}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, I_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{array}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $V_{\text {OUt(0) }}$ | Logical "0" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{array}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & v \\ & v \end{aligned}$ |
| Output Drive (See 54C/74C Family Characteristics Data Sheet) (Short Circuit Current) |  |  |  |  |  |  |
| Isource | Output Source Current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {IN }(0)}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \end{aligned}$ | -1.75 |  |  | mA |
| Isource | Output Source Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(O)}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, V_{O U T}=0 \mathrm{~V} \end{aligned}$ | -8.0 |  |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{N(1)}}=5.0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {OUT }}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 1.75 |  |  | mA |
| $\mathrm{I}_{\text {Sink }}$ | Output Sink Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(1)}=10 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 8.0 |  |  | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {pd0 }}, t_{\text {pd1 }}$ | Propagation Delay Time to a Logical " 0 " or Logical "1" from Data to $Y$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 170 \\ 80 \end{gathered}$ | $\begin{aligned} & 270 \\ & 130 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd0 }}, t_{\text {pd } 1}$ | Propagation Delay Time to a Logical " 0 " or Logical "1" from Data to W | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 200 \\ 90 \end{gathered}$ | $\begin{aligned} & 300 \\ & 140 \end{aligned}$ | ns ns |
| $t_{\text {pd0 }}, t_{\text {pd } 1}$ | Propagation Delay Time to a Logical " 0 " or Logical "1" from Strobe or Data Select to $Y$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 240 \\ & 110 \end{aligned}$ | $\begin{aligned} & 360 \\ & 170 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | (Note 2) |  | 5.0 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 3) |  | 50 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load $A C$ power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note AN-90.

## Switching Time Waveforms

## CMOS to CMOS ( $\mathbf{t}_{\text {pd1 }} \& \mathrm{t}_{\mathbf{p d O}}$ )




Truth Table

| InPUTS |  |  |  |  |  |  |  |  |  |  |  | OUTPUTS |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| c | B | A | Strobe | $\mathrm{D}_{0}$ | $\mathrm{D}_{1}$ | $\mathrm{D}_{2}$ | $\mathrm{D}_{3}$ | $\mathrm{D}_{4}$ | $\mathrm{D}_{5}$ | $\mathrm{D}_{6}$ | $\mathrm{D}_{7}$ | Y | w |
| $\times$ | x | x | 1 | $\times$ | x | x | X | x | x | x | x | 0 | 1 |
| 0 | 0 | 0 | 0 | 0 | x | x | x | x | x | $x$ | x | 0 | 1 |
| 0 | 0 | 0 | 0 | 1 | x | x | x | x | $x$ | x | x | 1 | 0 |
| 0 | 0 | 1 | 0 | x | 0 | x | x | x | x | x | x | 0 | 1 |
| 0 | 0 | 1 | 0 | x | 1 | x | x | x | x | $x$ | x | 1 | 0 |
| 0 | 1 | 0 | 0 | x | $x$ | 0 | $x$ | x | x | $x$. | x | 0 | 1 |
| 0 | 1 | 0 | 0 | x | x | 1 | x | x | x | $x$ | $x$ | 1 | 0 |
| 0 | 1 | 1 | 0 | x | x | $x$ | 0 | x | $x$ | x | x | 0 | 1 |
| 0 | 1 | 1 | 0 | x | x | x | 1 | x | x | x | x | 1 | 0 |
| 1 | 0 | 0 | 0 | x | $x$ | $x$ | x | 0 | $x$ | x | $x$ | 0 | 1 |
| 1 | 0 | 0 | 0 | x | x | $x$ | x | 1 | x | x | x | 1 | 0 |
| 1 | 0 | 1 | 0 | X | X | x | $x$ | x | 0 | X | $x$ | 0 | 1 |
| 1 | 0 | 1 | 0 | x | x | $x$ | x | x | 1 | x | x | 1 | 0 |
| 1 | 1 | 0 | 0 | x | x | $x$ | x | x | $x$ | 0 | x | 0 | 1 |
| 1 | 1 | 0 | 0 | x | $x$ | x | $x$ | x | $x$ | 1 | x | 1 | 0 |
| 1 | 1 | 1 | 0 | x | x | x | x | x | x | x | 0 | 0 | 1 |
| 1 | 1 | 1 | 0 | x | x | x | x | x | x | x | 1 | 1 | 0 |

## MM54C154/MM74C154 4-Line to 16-Line Decoder/Demultiplexer

## General Description

The MM54C154/MM74C154 one of sixteen decoder is a monolithic complementary MOS (CMOS) integrated circuit constructed with N - and P-channel enhancement transistors. The device is provided with two strobe inputs, both of which must be in the logical " 0 " state for normal operation. If either strobe input is in the logical "1" state, all 16 outputs will go to the logical "1" state.

To use the product as a demultiplexer, one of the strobe inputs serves as a data input terminal, while the other strobe input must be maintained in the logical " 0 " state. The information will then be transmitted to the selected output as determined by the 4 -line input address.

## Features

- Sùpply voltage range
- Tenth power TTL compatible
- High noise margin
- High noise immunity


## Applications

| ■ Automotive | ■ Alarm systems |
| :--- | :--- |
| ■ Data terminals | Industrial electronics |
| ■ Instrumentation | ■ Remote metering |
| ■ Medical electronics | ■ Computers |

- Medical electronics


## Logic and Connection Diagrams



| Absolute Maximum Ratings | (Note 1) |
| :---: | :---: |
| Voltage at Any Pin | -0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$ |
| Operating Temperature Range |  |
| MM54C154 | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM74C154 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Maximum V ${ }_{\text {cc }}$ Voltage | 18 V |
| Package Dissipation | 500 mW |
| Operating $\mathrm{V}_{\text {CC }}$ Range | 3 V to 15 V |
| Lead Temperature (Soldering, 10 sec .) | $300^{\circ} \mathrm{C}$ |

DC Electrical Characteristics Max.min. limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \hline v \\ & v \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | v |
| $\mathrm{V}_{\text {OUt(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{0}=-10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $\mathrm{V}_{\text {OUt(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | 0.5 1.0 | $\begin{aligned} & \mathrm{v} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{I}_{\mathbf{N}(1)}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{1 \times(0)}$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| Icc | Supply Current | $V_{C C}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| CMOS to LPTTL Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{array}$ | $\begin{aligned} & v_{c c}-1.5 \\ & v_{c c}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{v} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{array}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \mathrm{v} \\ & \mathrm{v} \end{aligned}$ |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{C C}=4.5 \mathrm{~V}, I_{O}=-100 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{C C}=4.75 \mathrm{~V}, I_{O}=-100 \mu \mathrm{~A} \end{array}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | v |
| $V_{\text {OUt(0) }}$ | Logical "0" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \grave{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad I_{O}=360 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ \hline \end{array}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & v \\ & v \end{aligned}$ |
| Output Drive (See 54C174C Family Characteristics Data Sheet) (Short Circuit Current) |  |  |  |  |  |  |
| Isource | Output Source Current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {IN }(0)}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \end{aligned}$ | -1.75 |  |  | mA |
| Isource | Output Source Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(0)}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \end{aligned}$ | -8.0 |  |  | mA |
| ${ }^{\text {ISINK}}$ | Output Sink Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{I N(1)}=5.0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=V_{C C} \end{aligned}$ | 1.75 |  |  | mA |
| $I_{\text {sink }}$ | Output Sink Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(1)}=10 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{C C} \end{aligned}$ | 8.0 |  |  | mA |

AC Electrical Characteristics
$T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd} 0}$ | Propagation Delay to a Logical " 0 " From Any Input to Any Output | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 275 \\ & 100 \end{aligned}$ | $\begin{aligned} & 400 \\ & 200 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pdo }}$ | Propagation Delay to a Logical "0" from G1 or G2 to Any Output | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | 275 100 | $\begin{aligned} & 400 \\ & 200 \end{aligned}$ | ns <br> ns |
| $\mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay to a Logical "1" from Any Input to Any Output | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | 265 100 | $\begin{aligned} & 400 \\ & 200 \end{aligned}$ | ns ns |
| $\mathrm{t}_{\text {pd1 }}$ | Propagation Delay to a Logical "1" from G1 or G2 to Any Output | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | 265 100 | $\begin{aligned} & 400 \\ & 200 \end{aligned}$ | $\begin{aligned} & \text { ns- } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance | (Note 2) |  | 5.0 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 3) |  | 60 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\mathrm{PD}}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note AN-90.

## Switching Time Waveforms



Truth Table

| INPUTS |  |  |  |  | OUTPUTS |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| G1 G2 | D | , C | B | A | 0 | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | 14 | 15 |
| L L | L | L | L | L | L | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H |
| L L | L | L | L | H | H | L | H | H | H | H | H | H | H | H | H | H | H | H | H | H |
| L L | L | L | H | L | H | H | L | H | H | H | H | H | H | H | H | H | H | H | H | H |
| L L | L | L | H | H | H | H | H | L | H | H | H | H | H | H | H | H | H | H | H | H |
| L L | L | H | L | L | H | H | H | H | L | H | H | H | H | H | H | H | H | H | H | H |
| L L | L | H | L | H | H | H | H | H | H | L | H | H | H | H | H | H | H | H | H | H |
| L L | L | H | H | L | H | H | H | H | H. | H | L | H | H | H | H | H | H | H | H | H |
| L L | L | H | H | H | H | H. | H | H | H | H | H | L | H | H | H | H | H | H | H | H |
| L L | H | L | L | L | H | H | H | H | H | H | H | H | L | H | H | H | H | H | H | H |
| L L | H | L | L | H | H | H | H | H | H | H | H | H | H | L | H | H | H | H | H | H |
| L L | H | L | H | L | H | H | H | H | H | H | H | H | H | H | L. | H | H | H | H | H |
| L L | H | L | H | H | H | H | H | H | H | H | H | H | H | H | H | L | H | H | H | H |
| L L | H | H | L | L | H | H | H | H | H | H | H | H | H | H | H | H | L | H | H | H |
| L L | H | H | L | H | H | H | H | H | H | H | H | H | H | H | H | H | H | L | H | H |
| L L | H | H | H | L | H | H | H | H | H | H | H | H | H | H | H | H | H | H | L | H |
| L L | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | L |
| L H | X | X | X | X | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H |
| H L | $x$ | X | $\times$ | $x$ | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H |
| H H | X | X | X | $\times$ | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H |

X = "Don't Care" Condition

## MM54C157/MM74C157 Quad 2-Input Multiplexers

## General Description

These multiplexers are monolithic complementary MOS (CMOS) integrated circuits constructed with N - and P-channel enhancement transistors. They consist of four 2-input multiplexers with common select and enable inputs. When the enable input is at logical " 0 " the four outputs assume the values as selected from the inputs. When the enable input is at logical " 1 ", the outputs assume logical " 0 ". Select decoding is done internally resulting in a single select input only.

Features

- Supply voltage range
a High noise immunity
- Low power
- Tenth power TTL compatible


## Logic Diagram

## Connection Diagram


top VIEW

## Truth Table

| ENABLE | SELECT | A | $\mathbf{B}$ | OUTPUT Y |
| :---: | :---: | :---: | :---: | :---: |
| $\mathbf{1}$ | X | X | X | 0 |
| 0 | 0 | 0 | X | 0 |
| 0 | 0 | 1 | X | 1 |
| 0 | 1 | X | 0 | 0 |
| 0 | 1 | X | 1 | 1 |



74L Compatibility

Guaranteed Noise Margin as a Function of $V_{\mathbf{C C}}$


Voltage at Any Pin
-0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
Operating Temperature Range
MM54C157
MM74C157
Storage Temperature Range
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$

Maximum $V_{C C}$ Voltage
18 V
Package Dissipation 500 mW
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
3 V to 15 V
Lead Temperature (Soldering, 10 sec.) $300^{\circ} \mathrm{C}$

DC Electrical Characteristics Max./min. limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 3.5 \\ 8 \end{gathered}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{I N(0)}$ | Logical " 0 " Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{gathered} 1.5 \\ 2 \end{gathered}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| Vout(1) | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Vout(0) | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | 0.5 1.0 | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $1 \mathrm{IN}(1)$ | Logical "1" Input Current | $V_{C C}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\operatorname{IN}(0)$ | Logical "0" Input Current | $V_{C C}=15 \mathrm{~V},$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| $\mathrm{Icc}$ | Supply Current | $V_{C C}=15 \mathrm{~V}$ |  | 0.05 | 60 | $\mu \mathrm{A}$ |
| CMOS to Tenth Power Interface |  |  |  |  |  |  |
| $V_{I N(1)}$ | Logical "1" Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V} \end{array}$ | $\begin{aligned} & V_{C C}-1.5 \\ & V_{C C}-1.5 \end{aligned}$ |  |  | V |
| $V_{I N(0)}$ | Logical " 0 " Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V} \end{array}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{array}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | V |
| Vout(O) | Logical "0" Output Voltage | $\begin{aligned} & 54 \mathrm{C} \quad V_{C C}=4.5 \mathrm{~V}, I_{O}=360 \mu \mathrm{~A} \\ & 74 \mathrm{C} \quad V_{C C}=4.75 \mathrm{~V}, I_{O}=360 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| Output Drive (See 54C/74C Family Characteristics Data Sheet) (Short Circuit Current) |  |  |  |  |  |  |
| ISOURCE | Output Source Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{I N(0)}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, V_{\text {OUT }}=0 \mathrm{~V} \end{aligned}$ | -1.75 |  |  | mA |
| Isource | Output Source Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{i N(0)}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, V_{O U T}=0 \mathrm{~V} \end{aligned}$ | -8.0 |  | - | mA |
| $I_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{I N(1)}=5.0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, V_{O U T}=V_{C C} \end{aligned}$ | 1.75 |  |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(1)}=10 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {OUT }}=V_{C C} \end{aligned}$ | 8.0 |  |  | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}$, unless otherwise specified.

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {pd0 }}, t_{\text {pd } 1}$ | Propagation Delay from Data to Output | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 150 \\ & 70 \end{aligned}$ | $\begin{aligned} & 250 \\ & 110 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd } 0}, t_{\text {pd } 1}$ | Propagation Delay from Select to Output | $\begin{aligned} & V_{c C}=5.0 \mathrm{~V} \\ & V_{c C}=10 \mathrm{~V} \end{aligned}$ | , | $\begin{gathered} 180 \\ 80 \end{gathered}$ | $\begin{aligned} & 300 \\ & 130 \end{aligned}$ | ns ns |
| $t_{\text {pd0 }}, t_{\text {pd } 1}$ | Propagation Delay from Enable to Output | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 180 \\ 80 \end{gathered}$ | $\begin{aligned} & 300 \\ & 130 \end{aligned}$ | ns ns |
| $\mathrm{CIN}_{\text {I }}$ | Input Capacitance | (Note 2) | . | 5 |  | pF |
| $\mathrm{CPD}^{\text {P }}$ | Power Dissipation Capacitance | (Note 3) |  | 20 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{P D}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note AN-90.

## MM54C160/MM74C160 Decade Counter with Asynchronous Clear MM54C161/MM74C161 Binary Counter with Asynchronous Clear MM54C162/MM74C162 Decade Counter with Synchronous Clear MM54C163/MM74C163 Binary Counter with Synchronous Clear

## Logic Waveforms




## Absolute Maximum Ratings <br> (Note 1)

Voltage at Any Pin
Operating Temperature Range
MM54C160/1/2/3
MM74C160/1/2/3
Storage Temperature Range
Maximum VCC Voltage
Package Dissipation
Operating $\mathrm{V}_{\mathrm{cc}}$ Range
-0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$

$$
\begin{array}{r}
-55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \\
-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \\
-65^{\circ} \mathrm{C} \text { to }+150^{\circ} \mathrm{C} \\
18 \mathrm{~V} \\
500 \mathrm{~mW} \\
3 \mathrm{~V} \text { to } 15 \mathrm{~V} \\
300^{\circ} \mathrm{C}
\end{array}
$$

Lead Temperature (Soldering, 10 sec .)

DC Electrical Characteristics
Max./min. limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\operatorname{IN}(1)}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Vout(1) | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $V_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | 0.5 1.0 | $\begin{aligned} & \text { V } \\ & \mathrm{V} \end{aligned}$ |
| $\mathrm{I}_{\mathrm{IN}(1)}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {IN(0) }}$ | Logical "0" Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| $I_{\text {cc }}$ | Supply Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| CMOS to LPTTL Interface |  |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V} \end{array}$ | $\left\|\begin{array}{\|c} \mathrm{V}_{\mathrm{Cc}}-1.5 \\ \mathrm{~V}_{\mathrm{Cc}}-1.5 \end{array}\right\|$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {IN }}(0)$ | Logical "0" Input Voltage | $\begin{aligned} & 54 \mathrm{C} \quad \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, ~ \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\text {OUT (1) }}$ | Logical "1" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{C C}=4.5 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{array}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Vout(0) | Logical "0" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+360 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+360 \mu \mathrm{~A} \end{array}$ | 1 |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Output Drive (See 54C/74C Family Characteristics Data Sheet) (Short Circuit Current) |  |  |  |  |  |  |
| $I_{\text {Source }}$ | Output Source Current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {IN(0) }}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \end{aligned}$ | 1.75 |  |  | mA |
| Isource | Output Source Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(0)}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, V_{O U T}=0 \mathrm{~V} \end{aligned}$ | 8.0 |  |  | mA |
| ISINK | Output Sink Current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}(1)}=5.0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 1.75 |  |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(1)}=10 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, V_{O U T}=V_{C C} \end{aligned}$ | 8.0 |  |  | mA |

AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {pd }}$ | Propagation Delay Time from Clock to Q | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 250 \\ & 100 \end{aligned}$ | $\begin{aligned} & 400 \\ & 160 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd }}$ | Propagation Delay Time from Clock to Carry Out | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 290 \\ & 120 \end{aligned}$ | $\begin{aligned} & 450 \\ & 190 \end{aligned}$ | ns ns |
| $t_{\text {pd }}$ | Propagation Delay Time from T Enable to Carry Out | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 180 \\ 70 \end{gathered}$ | $\begin{aligned} & 290 \\ & 120 \end{aligned}$ | ns ns |
| $t_{\text {pd }}$ | Propagation Time from Clear to Q (C160 and C161 only) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 190 \\ 80 \end{gathered}$ | $\begin{aligned} & 300 \\ & 150 \end{aligned}$ | ns ns |
| $t_{s}$ | Time prior to Clock that Data or Load must be Present | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 120 \\ 30 \end{gathered}$ |  | ns ns |
| $t_{S}$ | Time prior to Clock that Enable P or T must be Present | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 170 \\ 70 \end{gathered}$ | $\begin{aligned} & 280 \\ & 120 \end{aligned}$ | ns ns |
| $\mathrm{ts}_{5}$ | Time prior to Clock that Clear must be Present (162, 163 only) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 120 \\ 50 \end{gathered}$ | $\begin{gathered} 190 \\ 80 \end{gathered}$ | ns <br> ns |
| $t_{\text {w }}$ | Minimum Clock Pulses Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 90 \\ & 35 \end{aligned}$ | $\begin{gathered} 170 \\ 70 \end{gathered}$ | ns ns |
| $t_{r}, t_{f}$ | Maximum Clock Rise or Fall Time | $\begin{aligned} & V_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~N} \end{aligned}$ |  |  | $\begin{array}{r} 15 \\ 50 \end{array}$ | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \end{aligned}$ |
| $\mathrm{f}_{\text {MAX }}$ | Maximum Clock Frequency | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 2.0 \\ & 5.5 \end{aligned}$ | $\begin{aligned} & 3.0 \\ & 8.5 \end{aligned}$ |  | MHz <br> MHz |
| $C_{P D}$ | Power Dissipation Capacitance Input Capacitance | Note 3 <br> Note 2 |  | $\begin{aligned} & 95 \\ & 5.0 \end{aligned}$ |  | $\begin{aligned} & \mathrm{pF} \\ & \mathrm{pF} \end{aligned}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\mathrm{PD}}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note AN-90.

Logic Diagrams

MM74C160, MM74C162; Clear is Synchronous for the MM74C162


MM74C161, MM74C163; Clear is Synchronous for the MM74C163


## Switching Time Waveforms



Note 1: All input pulses are from generators having the following characteristics: $t_{r}=t_{f}=$ 20 ns PRR $\leq 1 \mathrm{MHz}$ duty cycle $\leq 50 \%, \mathrm{Z}_{\text {out }} \approx 50 \Omega$.
Note 2: All times are measured from $50 \%$ to $50 \%$.
Cascading Packages


## MM54C164/MM74C164 8-Bit Parallel-Out Serial Shift Register

## General Description

The MM54C164/MM74C164 shift registers are a monolithic complementary MOS (CMOS) integrated circuit constructed with N - and P -channel enhancement transistors. These 8 -bit shift registers have gated serial inputs and clear. Each register bit is a D-type master/slave flip flop. A high-level input enables the other input which will then determine the state of the flip flop.

Data is serially shifted in and out of the 8-bit register during the positive going transition of clock pulse. Clear is independent of the clock and accomplished by a low level at the clear input. All inputs are protected against electrostatic effects.

## Features

- Supply voltage range
- Tenth power TTL compatible
- High noise immunity
- Low power
- Medium speed operation

3 V to 15 V
drive 2 LPTTL loads
$0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.)
50 nW (typ.)
8.0 MHz (typ.)
with 10 V supply

## Applications

- Data terminals
- Industrial electronics
- Instrumentation
- Remote metering
- Medical electronics
- Computers


## Block Diagram



## Connection Diagram



Serial Inputs A and B

| INPUTS <br> $t_{n}$ |  | OUTPUT <br> $\mathbf{t}_{\mathrm{n}+1}$ |
| :---: | :---: | :---: |
| A | B | $\mathrm{a}_{\mathbf{A}}$ |
| 1 | 1 | 1 |
| 0 | 1 | 0 |
| 1 | 0 | 0 |
| 0 | 0 | 0 |

## Absolute Maximum Ratings（Note 1）

Voltage at Any Pin
Operating Temperature Range
MM54C164
MM74C164
Storage Temperature Range
Absolute Maximum VCC
Package Dissipation
Operating VCc Range
Lead Temperature（Soldering， 10 sec ．）
-0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
18 V
500 mW
3 V to 15 V $300^{\circ} \mathrm{C}$

DC Electrical Characteristics Max．Imin．limits apply across temperature range，unless otherwise noted．

|  | Parameter | Conditions | Min． | Typ． | Max． | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| －CMOS to CMOS | CMOS to CMOS |  |  |  |  |  |
| $\mathrm{V}_{\text {IN（1）}}$ | Logical＂1＂Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {IN（0）}}$ | Logical＂0＂Input Voltage | $\begin{aligned} & V_{c c}=5.0 \mathrm{~V} \\ & V_{\mathrm{cr}}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | V |
| $V_{\text {OUT（1）}}$ | Logical＂1＂Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{V}_{\text {OUT（0）}}$ | Logical＂0＂Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{I}_{\mathrm{N}(1)}$ | Logical＂1＂Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {（ }(0)}$ | Logical＂0＂Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V}$ | －1．0 | －0．005 |  | $\mu \mathrm{A}$ |
| ICC | Supply Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| CMOS to LPTTL Interface |  |  |  |  |  |  |
| $V_{\text {IN（1）}}$ | Logical＂1＂Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V} \end{array}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}-1.5 \\ & \mathrm{~V}_{\mathrm{CC}}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $V_{\text {IN（0）}}$ | Logical＂0＂Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V} \end{array}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\text {OUT（1）}}$ | Logical＂1＂Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{array}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | V |
| $\mathrm{V}_{\text {OUT（0）}}$ | Logical＂0＂Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V}, I_{\mathrm{O}}=360 \mu \mathrm{~A} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V}, I_{O}=360 \mu \mathrm{~A} \end{array}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \\ & \hline \end{aligned}$ | $\begin{aligned} & v \\ & v \end{aligned}$ |

Output Drive（See 54C／74C Family Characteristics Data Sheet）（Short Circuit Current）

| Isource | Output Source Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{1 N(0)}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \end{aligned}$ | －1．75 |  |  | mA |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Isource | Output Source Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(0)}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \end{aligned}$ | －8．0 |  |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{\text {IN(1) }}=5.0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {OUT }}=V_{C C} \end{aligned}$ | 1.75 |  |  | mA |
| $\mathrm{I}_{\text {İNK }}$ | Output Sink Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(1)}=10 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{O U T}=V_{C C} \end{aligned}$ | 8.0 |  |  | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Time to a Logical " 0 " or a Logical "1" from Clock to Q | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 230 \\ 90 \end{gathered}$ | $\begin{aligned} & 310 \\ & 120 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pdo }}$ | Propagation Delay Time to a Logical " 0 " from Clear to Q | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 280 \\ & 110 \end{aligned}$ | $\begin{aligned} & 380 \\ & 150 \end{aligned}$ | ns <br> ns |
| $t_{s}$ | Time Prior to Clock Pulse that Data Must be Present | $\begin{aligned} & V_{c C}=5.0 \mathrm{~V} \\ & V_{c c}=10 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 200 \\ 80 \end{gathered}$ | $\begin{gathered} 110 \\ 30 \end{gathered}$ |  | ns ns |
| $t_{H}$ | Time After Clock Pulse that Data Must be Held | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {maX }}$ | Maximum Clock Frequency | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 2.0 \\ & 5.5 \end{aligned}$ | $\begin{aligned} & 3 \\ & 8 \end{aligned}$ |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $t_{\text {w }}$ | Minimum Clear Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 150 \\ & 55 \end{aligned}$ | $\begin{gathered} 250 \\ 90 \end{gathered}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{r}, t_{f}$ | Maximum Clock Rise and Fall Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 15 \\ & 5.0 \end{aligned}$ |  |  | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Any Input (Note 2) |  | 5 |  | pF |
| $\mathrm{C}_{\mathrm{PD}}$ | Power Dissipation Capacitance | (Note 3) |  | 140 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{P D}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note AN-90.

## Switching Time Waveforms



## AC Test Circuit

## Typical Applications




## MM54C165/MM74C165 Parallel-Load 8-bit Shift Register

## General Description

The MM54C165/MM74C165 is an 8-bit serial shift register which shifts data from $Q_{A}$ to $Q_{H}$ when clocked. Parallel inputs to each stage are enabled by a low level at the shift/load input. Also included is a gated clock input and a complementary output from the eighth bit.

Clocking is accomplished through a 2 -input NOR-gate permitting one input to be used as a clock-inhibit function. Holding either of the clock inputs high inhibits clocking, and holding either clock input low with the shift/Ioad high enables the other clock input. Data transfer occurs on the positive edge of the clock. The clock inhibit input should be changed to a high level only while the clock input is high. Parallel loading is inhibited as long as the shift/load input is high. When taken low, data at the parallel inputs is loaded directly into the register independent of the state of the clock.

Features

- Wide supply voltage range 3.0 V to 15 V
- Guaranteed noise margin 1.0 V
- High noise immunity
- Low power TTL compatibility
$0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.)
fan out of 2 driving 74L
- Direct overriding load
- Gated clock inputs
- Fully static operation


## Connection Diagram



## Block Diagrams



[^3]| Absolute Maximum Ratings | （Note 1） |
| :---: | :---: |
| Voltage at Any Pin | -0.3 V to $\mathrm{V}_{\mathrm{Cc}}+0.3 \mathrm{~V}$ |
| Operating Temperature Range |  |
| MM54C165 | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM74C165 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Absolute Maximum $\mathrm{V}_{\mathrm{CC}}$ | 18 V |
| Package Dissipation | 500 mW |
| Operating $\mathrm{V}_{\text {CC }}$ Range | 3 V to 15 V |
| Lead Temperature（Soldering， 10 sec．） | $300^{\circ} \mathrm{C}$ |

DC Electrical Characteristics Max．／min．limits apply across temperature range，unless otherwise noted．

|  | Parameter | Conditions | Min． | Typ． | Max． | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN（1）}}$ | Logical＂1＂Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{c c}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \hline \mathrm{v} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\text {IN（0）}}$ | Logical＂0＂Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{c C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | v |
| $V_{\text {OUT（1）}}$ | Logical＂1＂Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{0}=-10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, I_{\mathrm{O}}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $\mathrm{V}_{\text {OUT（0）}}$ | Logical＂0＂Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{0}=+10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{cc}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $1{ }_{1 \times(1)}$ | Logical＂1＂Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| ${ }^{1} \mathrm{IN}(0)$ | Logical＂0＂Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V}$ | －1．0 | －0．005 |  | $\mu \mathrm{A}$ |
| Icc | Supply Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| CMOS to LPTTL Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN（1）}}$ | Logical＂1＂Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{C C}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V} \end{array}$ | $\begin{aligned} & v_{c c}-1.5 \\ & v_{c c}-1.5 \end{aligned}$ |  |  |  |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical＂0＂Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{array}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $v$ |
| $\mathrm{V}_{\text {OUt（1）}}$ | Logical＂1＂Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{array}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $v$ |
| $V_{\text {OUt }}$（ ） | Logical＂0＂Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{array}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| Output Drive（See 54C174C Family Characteristics Data Sheet）（Short Circuit Current） |  |  |  |  |  |  |
| Isource | Output Source Current （P－Channel） | $\begin{aligned} & V_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & T_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \end{aligned}$ | －1．75 | －3．3 |  | mA |
| Isource | Output Source Current （P－Channel） | $\begin{aligned} & V_{\mathrm{CC}}=10 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \end{aligned}$ | －8．0 | －15 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current <br> （N－Channel） | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 1.75 | 3.6 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current （ N －Channel） | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V} \\ & T_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 8.0 | 16 |  | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {pd0 }}, t_{\text {pd } 1}$ | Propagation Delay Time to a Logical " 0 " or Logical " 1 " from Clock or Load to Q or Q | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 200 \\ 80 \end{gathered}$ | $\begin{aligned} & 400 \\ & 200 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd } 0}, t_{\text {pd } 1}$ | Propagation Delay Time to a Logical " 0 " or Logical " 1 " from H to Q or Q | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 200 \\ 80 \end{gathered}$ | $\begin{aligned} & 400 \\ & 200 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{s}$ | Clock Inhibit Set-up Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 150 \\ 60 \end{gathered}$ | $\begin{aligned} & 75 \\ & 30 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{s}$ | Serial Input Set-up Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 50 \\ & 30 \end{aligned}$ | $\begin{aligned} & 25 \\ & 15 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {H }}$ | Serial Input Hold Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 50 \\ & 30 \end{aligned}$ | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ |  | ns ns |
| $t_{s}$ | Parallel Input Set-up Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 150 \\ & 60 \end{aligned}$ | $\begin{aligned} & 75 \\ & 30 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{H}}$ | Parallel Input Hold Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 50 \\ & 30 \end{aligned}$ | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ |  | ns ns |
| $t_{\text {w }}$ | Minimum Clock Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 70 \\ & 30 \end{aligned}$ | $\begin{aligned} & 200 \\ & 100 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {w }}$ | Minimum Load Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 85 \\ & 30 \end{aligned}$ | $\begin{gathered} 180 \\ 90 \end{gathered}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{f}_{\text {MAX }}$ | Maximum Clock Frequency | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 2.5 \\ & 5.0 \end{aligned}$ | $\begin{gathered} 6.0 \\ 12 \end{gathered}$ |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $t_{r}, t_{f}$ | Maximum Clock Rise and Fall Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 10 \\ & 5.0 \end{aligned}$ |  |  | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \end{aligned}$ |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance | (Note 2) |  | 5.0 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 3) |  | 65 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\mathrm{PD}}$ determines the no load $A C$ power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note AN-90.

## Switching Time Waveforms


$H=V_{I N}(T) . L=V_{I N}(0)$
$X=$ irrelevant
$i=$ transition from $V_{I N}(0)$ to $V_{I N}(1)$
a $. . . h=$ the level at data inputs $A$ thru $H$
$\mathrm{Q}_{\mathrm{A} O}, \mathrm{Q}_{\mathrm{BO}}, \mathrm{Q}_{\mathrm{HO}}=$ the level of $\mathrm{Q}_{\mathrm{A}}, \mathrm{Q}_{\mathrm{B}}$ or $\mathrm{Q}_{\mathrm{H}}$, before the indicated input conditions were established
$Q_{A n} . Q_{6 n}=$ the level of $Q_{A}$ or $Q_{6}$ before the most recent 1 transition of the clock

## Logic Waveforms



## MM54C173/MM74C173 TRI-STATE ${ }^{\circledR}$ Quad D Flip-Flop

## General Description

The MM54C173/MM74C173 TRI-STATE quad D flip tlop is a monolithic complementary MOS (CMOS) integrated circuit constructed with N - and P -channel enhancement transistors. The four D-type flip flops operate synchronously from a common clock. The TRI-STATE output allows the device to be used in bus-organized systems. The outputs are placed in the TRI-STATE mode when either of the two output disable pins are in the logic " 1 " level. The input disable allows the flip flops to remain in their present states without disrupting the clock. If either of the two input disables are taken to a logic " 1 " level, the Q outputs are fed back to the inputs and in this manner the flip flops do not change state.

Clearing is enabled by taking the input to a logic " 1 " level. Clocking occurs on the positive-going transition.

## Features

- Supply voltage range

3 V to 15 V

- Tenth power TTL compatible
- High noise immunity Drive 2 LPTTL loads
- Low power
- Medium speed operation
- High impedance TRI-STATE
- Input disable without gating the clock

Applications

- Automotive
- Alarm systems
- Data terminals
- Industrial electronics
- Instrumentation
- Remote metering
- Medical electronics
- Computers


## Logic Truth Table and Connection Diagrams



Truth Table (Both Output Disables Low)

| $t_{n}$ | $t_{n+1}$ |  |
| :--- | :---: | :---: |
| DATA INPUT DISABLE | DATA |  |
|  | INPUT | OUTPUT |
| Logic " 1 " on One or Both Inputs | $X$ | $Q_{n}$ |
| Logic " 0 " on Both Inputs | 1 | 1 |
| Logic " 0 " on Both Inputs | 0 | 0 |


| Absolute Maximum Ratings | (Note 1$)$ |
| :--- | ---: |
| Voltage at Any Pin | -0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$ |
| Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM54C173 | $-40^{\circ}$ to $+85^{\circ} \mathrm{C}$ |
| MM74C173 | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Storage Temperature Range | 18 V |
| Maximum $V_{\mathrm{CC}}$ Voltage | 500 mW |
| Package Dissipation | 3 V to 15 V |
| Operating $V_{\mathrm{CC}}$ Range | $300^{\circ} \mathrm{C}$ |

DC Electrical Characteristics Max./min. limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \hline \mathrm{V} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{1 \times(0)}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | v |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | v |
| $V_{\text {OUt(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | 0.5 1.0 | v |
| $\mathrm{I}_{\operatorname{IN}(1)}$ | Logical " 1 " Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {IN(0) }}$ | Logical "0" Input Current |  | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
|  | Output Current in High Impedance State | $\begin{aligned} & V_{C C}=15 \mathrm{~V}, V_{O}=15 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V}, V_{O}=0 \mathrm{~V} \end{aligned}$ | -1.0 | $\begin{aligned} & 0.001 \\ & 0.001 \end{aligned}$ | 1.0 | ${ }_{\mu \mathrm{A}}^{\mu \mathrm{A}}$ |
| ICC | Supply Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| Low Power TTL/CMOS Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IN}(1)}$ | Logical " 1 " Input Voltage | $\begin{array}{ll} \hline 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{array}$ | $\begin{aligned} & \hline \mathrm{V}_{\mathrm{CC}}-1.5 \\ & \mathrm{~V}_{\mathrm{CC}}-1.5 \end{aligned}$ |  |  |  |
| $\mathrm{V}_{1 \times(0)}$ | Logical " 0 " Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{array}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | v |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, I_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{array}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
|  | Logical "0" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{array}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $t_{\text {pd0 }}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Time to a Logical " 0 " or Logical "1" from Clock | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 500 |  | ns |
| Output Drive (See 54C/74C Family Characteristics Data Sheet) (Short Circuit Current) |  |  |  |  |  |  |
| Isource | Output Source Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{I N(0)}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \end{aligned}$ | -1.75 |  |  | mA |
| Isource | Output Source Current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\text {IN }(0)}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \end{aligned}$ | -8.0 |  |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN(1)}}=5.0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 1.75 |  |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN(1)}}=10 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 8.0 |  |  | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{p d 0}, t_{p d 1}$ | Propagation Delay Time to a Logical " 0 " or Logical " 1 " from Clock to Output | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 220 \\ 80 \end{gathered}$ | $\begin{aligned} & 400 \\ & 200 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{s}$ | Input Data Set-up Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 40 \\ & 15 \end{aligned}$ | $\begin{aligned} & 80 \\ & 30 \end{aligned}$ | ns ns |
| $t_{H}$ | Input Data Hold Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | 0 | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | $\begin{gathered} \text { ns } \\ 0 \end{gathered}$ | ns |
| $t_{s}$ | Input Disable Set-up Time, ts DISs | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | 100 35 | 200 70 | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{H}$ | Input Disable Hold Time, $\mathrm{t}_{\mathrm{H}}$ DISs | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | ns ns |
| $t_{1 H}, t_{0 H}$ | Delay from Output Disable to High Impedance State (from Logical " 1 " or Logical " 0 " Level) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, R_{\mathrm{L}}=10 \mathrm{k} \\ & V_{C C}=10 \mathrm{~V}, R_{\mathrm{L}}=10 \mathrm{k} \end{aligned}$ |  | $\begin{gathered} 170 \\ 70 \end{gathered}$ | $\begin{aligned} & 340 \\ & 140 \end{aligned}$ | ns ns |
| $t_{H 1}$ | Delay from Output Disable to Logical " 1 " Level (from High Impedance State) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 170 \\ 70 \end{gathered}$ | $\begin{aligned} & 340 \\ & 140 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {HO }}$ | Delay from Output Disable to Logical "0" Level (from High Impedance State) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 170 \\ 70 \end{gathered}$ | $\begin{aligned} & 340 \\ & 140 \end{aligned}$ | ns ns |
| $t_{p d 0}, t_{\text {pd1 }}$ | Propagation Delay from Clear to Output | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{c C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 240 \\ 90 \end{gathered}$ | $\begin{aligned} & 490 \\ & 180 \end{aligned}$ | ns ns |
| $f_{\text {max }}$ | Maximum Clock Frequency | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.0 \\ & 7.0 \end{aligned}$ | $\begin{gathered} 4.0 \\ 12 \end{gathered}$ |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $t_{W}$ | Minimum Clear Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 150 \\ & 70 \end{aligned}$ |  | ns ns |
| $t_{r}, t_{f}$ | Maximum Clock Rise and Fall Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 10 \\ & 5.0 \end{aligned}$ |  |  | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | (Note 2) |  | 5.0 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 3) |  |  |  |  |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note AN-90.

## Switching Time Waveforms



National Semiconductor

## MM54C174／MM74C174 Hex D Flip－Flop

## General Description

The MM54C174／MM74C174 hex D flip－flop is a monolithic complementary MOS（CMOS）integrated circuit con－ structed with N －and P －channel enhancement transistors． All have a direct clear input．Information at the D inputs meeting the setup time requirements is transferred to the Q outputs on the positive－going edge of the clock pulse． Clear is independent of clock and accomplished by a low level at the clear input．All inputs are protected by diodes To $V_{C C}$ and GND．

Features
■ Wide supply voltage range
3.0 V to 15 V
－Guaranteed noise margin
1.0 V
－High noise immunity
－Low power TTL compatibility

## Logic Diagrams



Connection Diagram


Truth Table

| INPUTS |  |  | OUTPUT |
| :---: | :---: | :---: | :---: |
| CLEAR | CLOCK | D | Q |
| L | X | X | L |
| H | $\uparrow$ | H | H |
| H | $\uparrow$ | L | L |
| H | L | X | Q |

## Absolute Maximum Ratings (Note 1)

Voltage at Any Pin
Operating Temperature Range
MM54C174
MM74C174
Storage Temperature Range
Package Dissipation
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
Absolute Maximum $\mathrm{V}_{\mathrm{CC}}$
Lead Temperature (Soldering, 10 sec .)
$-0.3 V$ to $V_{C c}+0.3 V$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
3.0 V to 15 V 18 V
$300^{\circ} \mathrm{C}$

DC Electrical Characteristics Max./min. limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical " 0 " Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | V |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | V |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{I}_{\mathrm{N}(1)}$ | Logical "1" Input Current | $\mathrm{V}_{C C}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $1 \mathrm{IN}(0)$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| $I_{\text {cc }}$ | Supply Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| CMOSILPTTL Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IN}(1)}$ | Logical "1" Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V} \end{array}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}-1.5 \\ & \mathrm{~V}_{\mathrm{CC}}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & v \\ & v \end{aligned}$ |
| $V_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{array}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{array}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | V |
| Vout(0) | Logical "0" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V}, I_{O}=360 \mu \mathrm{~A} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V}, I_{O}=360 \mu \mathrm{~A} \end{array}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & v \\ & v \end{aligned}$ |

Output Drive (See 54C/74C Family Characteristics Data Sheet) (Short Circuit Current)

| Isource | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \end{aligned}$ | -1.75 | -3.3 | mA |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $I_{\text {Source }}$ | Output Source Current (P-Channel) | $\begin{aligned} & V_{C C}=10 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \end{aligned}$ | -8.0 | -15 | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 1.75 | 3.6 | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 8.0 | 16 | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Delay Time to a Logical " 0 " or Logical " 1 " from Clock to Q | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 150 \\ & 70 \end{aligned}$ | $\begin{aligned} & 300 \\ & 110 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Delay Time to a Logical "0" from Clear | $\begin{aligned} & V_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 110 \\ & 50 \end{aligned}$ | $\begin{aligned} & 300 \\ & 110 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {s } 1}, t_{\text {so }}$ | Time Prior to Clock Pulse that Data must be Present | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 75 \\ & 25 \end{aligned}$ |  |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{H} 1}, \mathrm{t}_{\mathrm{HO}}$ | Time after Clock Pulse that Data must be Held | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & -10 \\ & -5.0 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{w}$ | Minimum Clock Pulse Width | $\begin{aligned} & V_{c c}=5.0 \mathrm{~V} \\ & V_{c C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 35 \end{aligned}$ | $\begin{aligned} & 250 \\ & 100 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| ${ }^{\text {tw }}$ | Minimum Clear Pulse Width | $\begin{aligned} & V_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & V_{\mathrm{cc}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 65 \\ & 35 \end{aligned}$ | $\begin{aligned} & 140 \\ & 70 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{r}, t_{f}$ | Maximum Clock Rise and Fall Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 15 \\ & 5.0 \end{aligned}$ | $\begin{aligned} & >1200 \\ & >1200 \end{aligned}$ |  | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \end{aligned}$ |
| $\mathrm{f}_{\text {MAX }}$ | Maximum Clock Frequency | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 2.0 \\ & 5.0 \end{aligned}$ | $\begin{aligned} & 6.5 \\ & 12 \end{aligned}$ |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Clear Input (Note 2) Any Other Input |  | $\begin{aligned} & 11 \\ & 5.0 \end{aligned}$ |  | $\begin{aligned} & \mathrm{pF} \\ & \mathrm{pF} \end{aligned}$ |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | Per Package (Note 3) |  | 95 | , | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note AN-90.

Switching Time Waveforms

CMOS to CMOS


## AC Test Circuit



## MM54C175/MM74C175 Quad D Flip-Flop

## General Description

The MM54C175/MM74C175 consists of four positiveedge triggered $D$ type flip-flops implemented with monolithic CMOS technology. Both are true and complemented outputs from each flip-flop are externally available. All four flip flops are controlled by a common clock and a common clear. Information at the D inputs meeting the set-up time requirements is transferred to the $Q$ outputs on the positive-going edge of the clock pulse. The clearing operation, enabled by a negative pulse at Clear input, clears all four Q outputs to logical " 0 " and Q's to logical " 1 ".

All inputs are protected from static discharge by diode clamps to $V_{c c}$ and GND.

## Features

| - Wide supply voltage range | 3.0 V to 15 V |
| :--- | ---: |
| - Guaranteed noise margin | 1.0 V |
| - High noise immunity | $0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.) |

- Low power TTL compatibility fan out of 2 driving 74L


## Connection Diagram and Truth Table



TOP VIEW

Each Flip-Flop

| INPUTS |  |  | OUTPUTS |  |
| :---: | :---: | :---: | :---: | :---: |
| CLEAR | CLOCK | D | Q | $\overline{\mathbf{Q}}$ |
| L | X | X | L | H |
| $H$ | $\uparrow$ | $H$ | $H$ | L |
| $H$ | $\uparrow$ | L | L | H |
| H | $H$ | X | NC | NC |
| H | L | X | NC | NC |

$H=$ High level
$L=$ Low level
$X=$ Irrelevant
$\uparrow=$ Transition from low to high level $N C=$ No change

## Logic Diagram



| Absolute Maximum Ratings | (Note 1$)$ |
| :--- | ---: |
| Voltage at Any Pin | -0.3 V to $\mathrm{V}_{\mathrm{cc}}+0.3 \mathrm{~V}$ |
| Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM54C175 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| MM74C175 | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Storage Temperature Range | 500 mW |
| Package Dissipation | 3 V to 15 V |
| Operating $V_{\mathrm{cc}}$ Range | 18 V |
| Absolute Maximum $\mathrm{V}_{\mathrm{CC}}$ | $300^{\circ} \mathrm{C}$ |

DC Electrical Characteristics Max.min. limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{v} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | v |
| $V_{\text {OUt(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{0}=-10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{v} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\text {Out }}$ (0) | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{\mathrm{O}}=+10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | 0.5 1.0 | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $\mathrm{I}_{1 /(1)}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {IN(0) }}$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{cc}}$ | Supply Current | $V_{C C}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |

## CMOS/LPTTL Interface

| $\mathrm{V}_{1 \times(1)}$ | Logical "1" Input Voltage | $\begin{aligned} & 54 \mathrm{C} \\ & 74 \mathrm{C} \end{aligned}$ | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \\ & V_{C C}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & V_{\mathrm{CC}}-1.5 \\ & V_{\mathrm{Cc}}-1.5 \end{aligned}$ |  | V |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & 54 \mathrm{C} \\ & 74 \mathrm{C} \end{aligned}$ | $\begin{aligned} & V_{c C}=4.5 \mathrm{~V} \\ & V_{c \mathrm{cc}}=4.75 \mathrm{~V} \end{aligned}$ |  | 0.8 0.8 | v |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & 54 \mathrm{C} \\ & 74 \mathrm{C} \end{aligned}$ | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V}, \quad I_{0}=-360 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  | v |
| $V_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & 54 \mathrm{C} \\ & 74 \mathrm{C} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{aligned}$ |  | 0.4 0.4 | v |

Output Drive (See 54C/74C Family Characteristics Data Sheet) (Short Circuit Current)

| $I_{\text {SOURCE }}$ | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \end{aligned}$ | -1.75 | -3.3 | mA |
| :---: | :---: | :---: | :---: | :---: | :---: |
| IsOURCE | Output Source Current (P-Channel) | $\begin{aligned} & V_{\mathrm{CC}}=10 \mathrm{~V} \\ & T_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \end{aligned}$ | -8.0 | -15 | mA |
| $\mathrm{I}_{\text {sink }}$ | Output Sink Current <br> ( N -Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {OUT }}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 1.75 | 3.6 | mA |
| $I_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 8.0 | 16 | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {pd }}$ | Propagation Delay Time to a Logical "0" or Logical "1" from Clock to Q or Q | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 190 \\ 75 \end{gathered}$ | $\begin{aligned} & 300 \\ & 110 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{p d}$ | Propagation Delay Time to a Logical " 0 " from Clear to Q | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 180 \\ 70 \end{gathered}$ | $\begin{aligned} & 300 \\ & 110 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {pd }}$ | Propagation Delay time to a Logical "1" from Clear to Q | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 230 \\ 90 \end{gathered}$ | $\begin{aligned} & 400 \\ & 150 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{s}$ | Time Prior to Clock Pulse that Data must be Present | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 100 \\ 40 \end{gathered}$ | $\begin{aligned} & 45 \\ & 16 \end{aligned}$ |  | ns ns |
| $t_{H}$ | Time After Clock Pulse that Data must be Held | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | $\begin{gathered} -11 \\ -4 \end{gathered}$ |  | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {w }}$ | Minimum Clock Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 130 \\ 45 \end{gathered}$ | $\begin{aligned} & 250 \\ & 100 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {w }}$ | Minimum Clear Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 120 \\ 45 \end{gathered}$ | $\begin{aligned} & 250 \\ & 100 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{r}}$ | Maximum Clock Rise Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 15 \\ & 5.0 \end{aligned}$ | $\begin{aligned} & 450 \\ & 125 \end{aligned}$ |  | $\begin{array}{r} \mu \mathrm{S} \\ \mu \mathrm{~S} \end{array}$ |
| $t_{f}$ | Maximum Clock Fall Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 15 \\ & 5.0 \end{aligned}$ | $\begin{aligned} & 50 \\ & 50 \end{aligned}$ |  | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \end{aligned}$ |
| $f_{\text {MAX }}$ | Maximum Clock Frequency | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 2.0 \\ & 5.0 \end{aligned}$ | $\begin{gathered} 3.5 \\ 10 \end{gathered}$ |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $\mathrm{CIN}_{\text {IN }}$ | Input Capacitance | Clear Input (Note 2) Any Other Input |  | $\begin{aligned} & 10 \\ & 5.0 \end{aligned}$ |  | $\begin{aligned} & \mathrm{pF} \\ & \mathrm{pF} \end{aligned}$ |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | Per Package (Note 3) |  | 130 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note AN-90.

Switching Time Waveforms


## MM54C192/MM74C192 Synchronous 4-Bit Up/Down Decade Counter <br> MM54C193/MM74C193 Synchronous 4-Bit Up/Down Decade Counter

## General Description

These up/down counters are monolithic complementary MOS (CMOS) integrated circuits. The MM54C192 and MM74C192 are BCD counters, while the MM54C193 and MM74C193 are binary counters.

Counting up and counting down is performed by two count inputs, one being held high while the other is clocked. The outputs change on the positio-going transition of this clock.

These counters feature preset inputs that are set when load is a logical " 0 " and a clear which forces all outputs to " 0 " when it is at a logical " 1 ". The counters also have carry and borrow outputs so that they can be cascaded using no external circuitry.

## Features

m High noise margin

- Tenth power TTL compatible

■ Wide supply range
a Carry and borrow outputs for N -bit cascading

* Asynchronous clear
* High noise immunity
$0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.)

Connection Diagram


Cascading Packages


Guaranteed Noise Margin as A Function of $V_{C C}$


| Absolute Maximum Ratings | (Note 1$)$ |
| :--- | ---: |
| Voltage at Any Pin | -0.3 V to $\mathrm{V}_{\mathrm{cC}}+0.3 \mathrm{~V}$ |
| Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM54C193 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| MM74C193 | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Storage Temperature Range | 500 mW |
| Package Dissipation | 3.0 V to 15 V |
| Operating $\mathrm{V}_{\mathrm{CC}}$ Range | 18 V |
| Absolute Maximum $\mathrm{V}_{\mathrm{CC}}$ | $300^{\circ} \mathrm{C}$ |

DC Electrical Characteristics Max./min. limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{c c}=5.0 \mathrm{~V} \\ & V_{c c}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical " 0 " Input Voltage | $\begin{aligned} & V_{c c}=5.0 \mathrm{~V} \\ & V_{c c}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | 0.5 1.0 | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{I}_{\mathrm{IN}(1)}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{N}(0)}$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ | 1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{CC}}$ | Supply Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| CMOS to Tenth Power Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IN}(1)}$ | Logical "1" Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & V_{\mathrm{CC}}=4.75 \mathrm{~V} \end{array}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}-1.5 \\ & \mathrm{~V}_{\mathrm{CC}}-1.5 \end{aligned}$ |  | , | $\begin{aligned} & \mathrm{V} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical "0" Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V} \end{array}$ |  |  | $\begin{gathered} 0.8 \\ 0.8 \end{gathered}$ | $\begin{aligned} & \text { V } \\ & \mathrm{V} \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{C C}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{array}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V}, I_{O}=360 \mu \mathrm{~A} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V}, I_{O}=360 \mu \mathrm{~A} \end{array}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |

Output Drive (See 54C/74C Family Characteristics Data Sheet) (Short Circult Current)

| Isource | Output Source Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{\text {IN(0) }}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \end{aligned}$ | -1.75 |  |  | mA |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Isource | Output Source Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(0)}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, V_{O U T}=0 \mathrm{~V} \end{aligned}$ | -8.0 |  |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{I N(1)}=5.0 \mathrm{~V} \\ & T_{A}=25^{\circ}, V_{O U T}=V_{C C} \end{aligned}$ | 1.75 |  |  | mA |
| $I_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(1)}=10 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, V_{O U T}=V_{C C} \end{aligned}$ | 8.0 |  |  | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Delay Time to Q from Count Up or Down | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 250 \\ & 100 \end{aligned}$ | $\begin{aligned} & 400 \\ & 160 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {pd }}$ | Propagation Delay Time to Borrow from Count Down | $\begin{aligned} & V_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 120 \\ 50 \end{gathered}$ | $\begin{gathered} 200 \\ 80 \end{gathered}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd }}$ | Propagation Delay Time to Carry from Count Up | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 120 \\ 50 \end{gathered}$ | $\begin{gathered} 200 \\ 80 \end{gathered}$ | ns <br> ns |
| $\mathrm{t}_{5}$ | Time Prior to Load that Data must be Present | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 100 \\ 30 \end{gathered}$ | $\begin{gathered} 160 \\ 50 \end{gathered}$ | ns ns |
| $t_{\text {w }}$ | Minimum Clear Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 300 \\ & 120 \end{aligned}$ | $\begin{aligned} & 480 \\ & 190 \end{aligned}$ | ns ns |
| $t_{w}$ | Minimum Load Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 100 \\ 40 \end{gathered}$ | $\begin{aligned} & 160 \\ & 65 \end{aligned}$ | ns ns |
| $t_{p d 0}, t_{p d 1}$ | Propagation Delay Time to $\mathbf{Q}$ from Load | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 300 \\ & 120 \end{aligned}$ | $\begin{aligned} & 480 \\ & 190 \end{aligned}$ | ns <br> ns |
| $t_{w}$ | Minimum Count Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 120 \\ 35 \end{gathered}$ | $\begin{gathered} 200 \\ 80 \end{gathered}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{f}_{\text {MAX }}$ | Maximum Count Frequency | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 2.5 \\ 6 \end{gathered}$ | $\begin{gathered} 4 \\ 10 \end{gathered}$ |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $t_{r}, t_{f}$ | Count Rise and Fall Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{gathered} 15 \\ 5 \end{gathered}$ | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | (Note 2) |  | 5 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 3) |  | 100 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note AN-90.

## Timing Diagrams



Note I: Clear outputs to zero.
Note II: Load (preset) to binary thirteen.
Note III: Count up to fourten, fifteen, carry, zero, one and two.
Note IV: Count down to one, zero, borrow, fifteen, fourteen, and thirteen.


Note I: Clear outputs to zero.
Note II: Load (preset) to BCD seven
oote III: Count up to eight, nine, carry, zero, one, and two.
Note IV: Count down to one, zero, borrow, nine, eight, and seven.

Schematic Diagrams


## MM54C195／MM74C195 4－bit Registers

## General Description

The MM54C195／MM74C195 CMOS 4－bit registers feature parallel inputs，parallel outputs，J－K serial inputs，shift／ load control input and a direct overriding clear．The fol－ lowing two modes of operation are possible：

Parallel Load
Shift in direction $Q_{A}$ towards $Q_{D}$
Parallel loading is accomplished by applying the four bits of data and taking the shift／load control of input low．The data is loaded into the associated flip－flops and appears at the outputs after the positive transition of the clock in－ put．During parallel loading，serial data flow is inhibited．

Serial shifting is accomplished synchronously when the shift／load control input is high．Serial data for this mode is entered at the J－K inputs．These inputs allow the first stage to perform as a J－K，D，or T－type flip flop as shown in the truth table．

Features
－Medium speed operation
－High noise immunity
－Low power
－Tenth power TTL compatible
－Supply voltage range
－Synchronous paràllel load
－Parallel inputs and outputs from each flip－flop
－Direct overriding clear
－J and K inputs to first stage
－Complementary outputs from last stage
－Positive－edge triggered clocking
－Diode clamped inputs to protect against static charge
8.5 MHz （typ．）with 10 V supply and 50 pF load $0.45 \mathrm{~V}_{\mathrm{CC}}$（typ．） 100 nW（typ．）
drive 2 LPTTL loads
3 V to 15 V

## Applications

－Automotive
－Alarm systems
－Data terminals
－Instrumentation
－Medical electronics
－Remote metering
－Industrial electronics
－Computers

Schematic and Connection Diagrams


## Absolute Maximum Ratings (Note 1)

Voltage at Any Pin
Operating Temperature Range
MM54C195
MM74C195
Storage Temperature Range
Package Dissipation
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
Absolute Maximum $\mathrm{V}_{\mathrm{Cc}}$
Lead Temperature (Soldering, 10 sec .)
-0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$

$$
-55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C}
$$

$$
-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C}
$$

$$
-65^{\circ} \mathrm{C} \text { to }+150^{\circ} \mathrm{C}
$$

DC Electrical Characteristics Max./min. limits apply across temperature range, unless otherwise noted.


AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {pd }}$ | Propagation Delay Time to a Logical " 0 " or Logical "1" from Clock to Q or Q | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 150 \\ & 75 \end{aligned}$ | $\begin{aligned} & 300 \\ & 130 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Delay Time to a Logical " 0 " or Logical "1" from Clear to Q or Q | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 150 \\ 50 \end{gathered}$ | $\begin{aligned} & 300 \\ & 130 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{t}_{\mathrm{s}}$ | Time Prior to Clock Pulse that Data must be Present | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 80 \\ & 35 \end{aligned}$ | $\begin{gathered} 200 \\ 70 \end{gathered}$ | ns ns |
| $t_{s}$ | Time Prior to Clock Pulse that Shift/Load must be Present | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 110 \\ 60 \end{gathered}$ | $\begin{gathered} 150 \\ 90 \end{gathered}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{H}$ | Time After Clock Pulse that Data must be Held | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} -10 \\ -5.0 \end{array}$ | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {w }}$ | Minimum Clear Pulse Width ( $\mathrm{t}_{\mathrm{WL}}=\mathrm{t}_{\mathrm{WH}}$ ) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 100 \\ 50 \end{gathered}$ | $\begin{aligned} & 200 \\ & 100 \end{aligned}$ | ns <br> ns |
| $t_{\text {w }}$ | Minimum Clear Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 90 \\ & 40 \end{aligned}$ | $\begin{aligned} & 130 \\ & 60 \end{aligned}$ | ns ns |
| $t_{r}, t_{f}$ | Maximum Clock Rise and Fall Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 5.0 \\ & 2.0 \end{aligned}$ |  |  | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \end{aligned}$ |
| $\mathrm{f}_{\text {MAX }}$ | Maximum Input Clock Frequency | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 2.0 \\ & 5.5 \end{aligned}$ | $\begin{aligned} & 3.0 \\ & 8.5 \end{aligned}$ |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | (Note 2) |  | 5.0 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 3) |  | 100 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note AN-90.

## Switching Time Waveforms



## MM54C200/MM74C200 256-Bit TRI-STATE ${ }^{\circledR}$ Random Access Read/Write Memory

## General Description

The MM54C200/MM74C200 is a 256-bit random access read/write memory. Inputs consist of eight address lines, and three chip enables. The eight binary address inputs are decoded internally to select each of the 256 locations. The internal address register, latches, and address information are on the positive to negative edge of $\overline{\mathrm{CE}}_{3}$. The TRI-STATE data output line, working in conjunction with $\overline{\mathrm{CE}}_{1}$ or $\overline{\mathrm{CE}}_{2}$ inputs, provides for easy memory ex pansion.

Address Operation: Address inputs must be stable $t_{S A}$ prior to the positive to negative transition of $\overline{\mathrm{CE}}_{3}$. It is therefore unnecessary to hold address information stable for more than $t_{\text {HA }}$ after the memory is enabled (positive to negative transition).

Note: The timing is different from the DM74200 in that a positive to negative transition of the $\overline{\mathrm{CE}}_{3}$ must occur for the memory to be selected.

Read Operation: The data is read out by selecting the proper address and bringing $\overline{\mathrm{CE}}_{3}$ low and $\overline{\mathrm{WE}}$ high.

Holding either $\overline{\mathrm{CE}}_{1}, \overline{\mathrm{CE}}_{2}$, or $\overline{\mathrm{CE}}_{3}$ at a high level forces the output into TRI-STATE. When used in bus-organized systems, $\overline{\mathrm{CE}}_{1}$, or $\overline{\mathrm{CE}}_{2}$, a TRI-STATE control provides for fast access times by not totally disabling the chip.

Write Operation: Data is written into the memory with $\overline{C E}_{3}$ low and $\overline{W E}$ low. The state of $\overline{C E}_{1}$ or $\overline{\mathrm{CE}}_{2}$ has no effect on the write cycle. The output assumes TRI-STATE with WE low.

## Features

Wide supply voltage range
3.0 V to 15 V

Guaranteed noise margin
1.0 V

- High noise immunity
- TTL compatibility
- Low power
fan out of 1 fan out of 1 driving standard TTL 500 nW (typ.)

See page 4-7
for detailed specifications

## MM54C221/MM74C221 Dual Monostable Multivibrator

## General Description

The MM54C221/MM74C221 dual monostable multivibrator is a monolithic complementary MOS integrated circuit. Each multivibrator features a negative-transtiontriggered input and a positive-transition-triggered input, either of which can be used as an inhibit input, and a clear input.

Once fired, the output pulses are independent of further transitions of the $A$ and $B$ inputs and are a function of the external timing components $\mathrm{C}_{\text {EXT }}$ and $\mathrm{R}_{\text {EXT }}$. The pulse width is stable over a wide range of temperature and $V_{C C}$.

Pulse stability will be limited by the accuracy of external timing components. The pulse width is approximately defined by the relationship $t_{\text {W(OUT) }} \approx C_{E X T} R_{E X T}$. For further information and applications, see AN-138.

## Features

- Wide supply voltage range
4.5 V to 15 V
- Guaranteed noise margin
- High noise immunity
- Low power TTL compatibility
$0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.)
fan out of 2 driving 74L

Connection Diagrams

Timing Component



Truth Table

| INPUTS |  |  | OUTPUTS |  |
| :---: | :---: | :---: | :---: | :---: |
| CLEAR | A | B | 0 | $\overline{\mathrm{a}}$ |
| L | $\times$ | x | L | H |
| x | H | X | L | H |
| x | x | L | L | H |
| H | L | $\uparrow$ | $\Omega$ | U |
| H | $\downarrow$ | H | $\Omega$ | ־ธ |

$H=$ High level
$L=$ Low level
$\uparrow=$ Transition from low to high
$t=$ Transition from high to low
$\Omega=$ One high level pulse
$\square$ = One low level pulse
$X=$ Irrelevant

## Absolute Maximum Ratings <br> (Note 1)

Voltage at Any Pin
Operating Temperature Range

## MM54C221

MM74C221
Storage Temperature Range
Package Dissipation
Operating $V_{C C}$ Range
Absolute Maximum $\mathrm{V}_{\mathrm{CC}}$
$\mathrm{R}_{\mathrm{EXT}} \geqslant 80 \mathrm{~V}_{\mathrm{CC}}(\Omega)$
Lead Temperature (Soldering, 10 sec .)

```
-55%}\textrm{C}\mathrm{ to }+12\mp@subsup{5}{}{\circ}\textrm{C
    -40}\mp@subsup{}{}{\circ}\textrm{C}\mathrm{ to }+8\mp@subsup{5}{}{\circ}\textrm{C
    -65%}\textrm{C}\mathrm{ to +150}\mp@subsup{}{}{\circ}\textrm{C
        500 mW
    4.5V to 15V
        18V
                            300 %
```

DC Electrical Characteristics Max.min. limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{1 \mathrm{~N}(0)}$ | Logical " 0 " Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {OUT (1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Vout(0) | Logical "0" Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} ; \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | 0.5 1.0 | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{I}_{\mathrm{N}(1)}$ | Logical "1" Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\boldsymbol{I N}(0)$ | Logical "0" Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| ICC | Supply Current (Standby) | $\begin{aligned} & V_{C C}=15 \mathrm{~V}, R_{E X T}=\infty, \\ & \text { Q1, } \mathrm{Q} 2=\text { Logic "0" (Note 3) } \end{aligned}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| Icc | Supply Current (During Output Pulse) | $\begin{aligned} & V_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{Q} 1=\text { Logic " } 1 ", \\ & \text { Q2 = Logic "0" (Figure 4) } \end{aligned}$ |  | 15 |  | mA |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}==5.0 \mathrm{~V}, \mathrm{Q} 1=\text { Logic " } 1 \text { ", } \\ & \mathrm{Q} 2=\text { Logic " } 0 \text { " (Figure } 4 \text { ) } \end{aligned}$ |  | 2.0 |  | mA |
|  | Leakage Current at $\mathrm{R} / \mathrm{C}_{\mathrm{EXT}}$ Pin | $\mathrm{V}_{\text {CC }}=15 \mathrm{~V}, \mathrm{~V}_{\text {CEXT }}=5.0 \mathrm{~V}$ |  | 0.01 | 3.0 | $\mu \mathrm{A}$ |
| CMOS/LPTTL Interface |  |  |  |  |  |  |
| $V_{1 N(1)}$ | Logical "1" Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V} \end{array}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{Cc}}-1.5 \\ & \mathrm{~V}_{\mathrm{cc}}-1.5 \end{aligned}$ |  |  | V V |
| $V_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V} \end{array}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | V |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{C C}=4.5 \mathrm{~V}, \quad I_{O}=-360 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, I_{O}=-360 \mu \mathrm{~A} \end{array}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V}, \quad I_{\mathrm{O}}=360 \mu \mathrm{~A} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V}, I_{\mathrm{O}}=360 \mu \mathrm{~A} \end{array}$ |  |  | 0.4 0.4 | V |

## Output Drive (See 54C/74C Family Characteristics Data Sheet) (Short Circuit Current)



AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {pd A,B }}$ | Propagation Delay from Trigger Input (A,B) to Output $\mathbf{Q}, \bar{Q}$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{c C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 250 \\ & 120 \end{aligned}$ | $\begin{aligned} & 500 \\ & 250 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd CL }}$ | Propagation Delay from Clear Input (CL) to Output Q, $\bar{Q}$ | $\begin{aligned} & V_{c C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 250 \\ & 120 \end{aligned}$ | 500 250 | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{s}$ | Time Prior to Trigger Input (A,B) that Clear must be Set | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 150 \\ & 60 \end{aligned}$ | $\begin{aligned} & 50 \\ & 20 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {W(A, B })}$ | Trigger Input (A,B) Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 150 \\ & 70 \end{aligned}$ | $\begin{aligned} & 50 \\ & 30 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {W(CL) }}$ | Clear Input (CL) Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 150 \\ & 70 \end{aligned}$ | $\begin{aligned} & 50 \\ & 30 \end{aligned}$ |  | ns ns |
| $t_{\text {W(OUT }}$ | Q or $\overline{\mathbf{Q}}$ Output Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, R_{\mathrm{EXT}}=10 \mathrm{k}, \\ & \mathrm{C}_{\mathrm{EXT}}=0 \mathrm{pF} \end{aligned}$ |  | 900 |  | ns |
|  |  | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, \mathrm{R}_{\mathrm{EXT}}=10 \mathrm{k} \\ & \mathrm{C}_{\mathrm{EXT}}=0 \mathrm{pF} \end{aligned}$ |  | 350 |  | ns |
|  |  | $\begin{aligned} & V_{C C}=15 \mathrm{~V}, R_{E X T}=10 \mathrm{k} \\ & \mathrm{C}_{\mathrm{EXT}}=0 \mathrm{pF} \end{aligned}$ |  | 320 |  | ns |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{R}_{\text {EXT }}=10 \mathrm{k}, \\ & \mathrm{C}_{\mathrm{EXT}}=1000 \mathrm{pF} \quad(\text { Fig. } 1) \end{aligned}$ | 9.0 | 10.6 | 12.2 | $\mu \mathrm{S}$ |
|  | ! | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, R_{E X T}=10 \mathrm{k}, \\ & C_{E X T}=1000 \mathrm{pF} \quad(\text { Fig. 1) } \end{aligned}$ | 9.0 | 10 | 11 | $\mu \mathrm{S}$ |
|  |  | $\begin{aligned} & V_{C C}=15 \mathrm{~V}, R_{E X T}=10 \mathrm{k}, \\ & C_{E X T}=1000 \mathrm{pF} \quad(\text { Fig. } 1) \end{aligned}$ | 8.9 | 9.8 | 10.8 | $\mu \mathrm{S}$ |
|  |  | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, R_{E X T}=10 \mathrm{k}, \\ & C_{E X T}=0.1 \mu \mathrm{~F} \quad \text { (Fig. 2) } \end{aligned}$ | 900 | 1020 | 1200 | $\mu \mathrm{S}$ |
|  |  | $\begin{aligned} & \mathrm{V}_{C C}=10 \mathrm{~V}, \mathrm{R}_{\mathrm{EXT}}=10 \mathrm{k}, \\ & \mathrm{C}_{\mathrm{EXT}}=0.1 \mu \mathrm{~F} \quad \text { (Fig. 2) } \end{aligned}$ | 900 | 1000 | 1100 | $\mu \mathrm{S}$ |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{R}_{\mathrm{EXT}}=10 \mathrm{k}, \\ & \mathrm{C}_{\mathrm{EXT}}=0.1 \mu \mathrm{~F} \quad \text { (Fig.2) } \end{aligned}$ | 900 | 990 | 1100 | $\mu \mathrm{S}$ |
| $\mathrm{R}_{\text {ON }}$ | ON Resistance of Transistor between R/C $C_{E X T}$ to $\mathrm{C}_{\mathrm{EXT}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}(\text { Note 4) } \\ & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V} \quad(\text { Note 4) } \\ & \mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V} \quad(\text { Note 4) } \end{aligned}$ |  | $\begin{gathered} 50 \\ 25 \\ 16.7 \end{gathered}$ | $\begin{aligned} & 150 \\ & 65 \\ & 45 \end{aligned}$ | $\begin{aligned} & \Omega \\ & \Omega \\ & \Omega \end{aligned}$ |
|  | Output Duty Cycle | $\begin{aligned} & R=10 \mathrm{k}, \mathrm{C}=1000 \mathrm{pF} \\ & \mathrm{R}=10 \mathrm{k}, \mathrm{C}=0.1 \mu \mathrm{~F} \\ & \text { (Note 5) } \end{aligned}$ |  |  | $\begin{aligned} & 90 \\ & 90 \end{aligned}$ | $\begin{aligned} & \text { \% } \\ & \% \end{aligned}$ |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance | R/C $\mathrm{C}_{\mathrm{EXT}}$ Input (Note 2) Any Other Input (Note 2) |  | $\begin{aligned} & 15 \\ & 5.0 \end{aligned}$ | 25 | $\begin{aligned} & \mathrm{pF} \\ & \mathrm{pF} \end{aligned}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: In Standby ( $\mathrm{Q}=$ Logic " 0 ") the power dissipated equals the leakage current plus $\mathrm{V}_{\mathrm{CC}} / \mathrm{R}_{\mathrm{EXT}}$.
Note 4: See AN-138 for detailed explanation of RON.
Note 5: Maximum output duty cycle $=\mathrm{R}_{\mathrm{EXT}} / \mathrm{R}_{\mathrm{EXT}}+1000$.

## Typical Performance Characteristics

## Figure 1

Typical Distribution of Units for Output Pulse Width


Figure 3
Typical Variation in Output Pulse Width vs Temperature


## Figure 2

Typical Distribution of Units for Output Pulse Width


Figure 4
Typical Power Dissipation per Package


Switching Time Waveforms


## MM54C240/MM74C240 Inverting MM54C244/MM74C244 Non-Inverting <br> Octal Buffers and Line Drivers with TRI-STATE® Outputs

## General Description

These octal buffers and line drivers are monolithic complementary MOS (CMOS) integrated circuits with TRISTATE ${ }^{( }$outputs. These outputs have been specially designed to drive highly capacitive loads such as busoriented systems. These devices have a fan-out of 6 low power Schottky loads. A high logic level on the output disable control input $G$ makes the outputs go into the high impedance state. For improved TTL input compatibility see MM74C941.

## Features

■ Wide supply voltage range ( 3 V to 15 V )

- High noise immunity ( $0.45 \mathrm{~V}_{\mathrm{CC}}$ typ)
- Low power consumption
- High capacitive load drive capability
- TRI-STATE outputs
- Input protection
- TTL compatibility
- 20-pin dual-in-line package
- High speed 25 ns (typ.) @ 10V, 50 pF (MM74C244)


MM54C244/MM74C244


MM54C240/MM74C240
Dual-In-Line Package


MM54C244/MM74C244
Dual-In-Line Package


TOP VIEW

## Absolute Maximum Ratings (Note 1)

Voltage at Any Pin
Operating Temperature Range MM54C240, MM54C244 MM74C240, MM74C244
Storage Temperature Range
Package Dissipation
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
Absolute Maximum $\mathrm{V}_{\mathrm{Cc}}$
Lead Temperature (Soldering, 10 seconds)
-0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
3 V to 15 V
18 V
$300^{\circ} \mathrm{C}$

## DC Electrical Characteristics

Min/max limits apply across temperature range, unless otherwise noted.

| Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS TO CMOS |  |  |  |  |  |
| Logical "1" Input Voltage ( $\mathrm{V}_{\mathrm{IN}(1)}$ ) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & v \\ & v \end{aligned}$ |
| Logical "0" Input Voltage ( $\mathrm{V}_{\text {IN(0) }}$ ) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | : | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Logical '1"' Output Voltage ( $\mathrm{V}_{\text {OUT(1) }}$ ) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, I_{\mathrm{O}}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & v \\ & v \end{aligned}$ |
| Logical '0' Output Voltage ( $\mathrm{V}_{\text {OUT(0) }}$ ) | $\begin{aligned} & \mathrm{V}_{C C}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Logical "1" Input Current ( $\operatorname{lin}_{\underline{N}(1)}$ ) | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| Logical "0" Input Current ( $\left.l_{\mathrm{IN}(0)}\right)$ | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| Supply Current (ICC) | $V_{C C}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| CMOSILPTTL INTERFACE |  |  |  |  |  |
| Logical "1" Input Voltage ( $\mathrm{V}_{\text {IN(1) }}$ ) | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}-1.5 \\ & \mathrm{~V}_{\mathrm{CC}}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| Logical '0' Input Voltage ( $\mathrm{V}_{\text {IN(0) }}$ ) | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Logical " 1 " Output Voltage ( $\mathrm{V}_{\text {OUT(1) }}$ ) | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-450 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-450 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}-0.4 \\ & \mathrm{~V}_{\mathrm{CC}}-0.4 \end{aligned}$ |  |  | $\begin{aligned} & v \\ & v \end{aligned}$ |
|  | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-2.2 \mathrm{~mA} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-2.2 \mathrm{~mA} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & v \\ & v \end{aligned}$ |
| Logical '0' Output Voltage ( $\mathrm{V}_{\text {OUT(0) }}$ ) | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=2.2 \mathrm{~mA} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=2.2 \mathrm{~mA} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & v \\ & v \end{aligned}$ |

## OUTPUT DRIVE (See 54C/74C Family Characteristics Data Sheet) (Short Circuit Current)

Output Source Current (Isource) (P-Channel)

Output Sink Current (ISINK) (N-Channel)

$$
\begin{aligned}
& \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\
& T_{A}=25^{\circ} \mathrm{C} \\
& \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\
& \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\
& \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=\mathrm{V}_{\mathrm{CC}} \\
& \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\
& \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=\mathrm{V}_{\mathrm{CC}} \\
& T_{A}=25^{\circ} \mathrm{C}
\end{aligned}
$$

$$
\begin{array}{l|l}
V_{C C}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} & -36.0
\end{array}
$$

| -14.0 | -30.0 |  | mA |
| :---: | :---: | :---: | :---: |
| -36.0 | -70.0 |  | mA |
| 12.0 | 20.0 |  | mA |
| 48.0 | 70.0 |  | mA |

AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

| Parameter |  | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {Pd(1) }}, \mathrm{t}_{\mathrm{Pd}(0)}$ | Propagation Delay (Data In to Out) MM54C240/MM74C240 |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 60 | 90 | ns |
|  |  | $V_{C C}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 40 | 70 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF}$ |  | 80 | 110 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF}$ |  | 60 | 90 | ns |
|  | MM54C244/MM74C244 | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 45 | 70 | ns |
|  |  | $V_{C C}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 25 | 50 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF}$ |  | 60 | 90 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF}$ |  | 40 | 70 | ns |
| $\mathrm{t}_{1 H}, \mathrm{t}_{0 \mathrm{H}}$ | Propagation Delay Output Disable to High Impedance State (from a Logic Level) | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  |  |  |  |
|  |  | $V_{\text {cC }}=5 \mathrm{~V}$ |  | 45 | 80 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ |  | 35 | 60 | ns |
| $t_{H}, t_{H}$ | Propagation Delay Output Disable to Logic Level (from High Impedance State) | $R_{L}=1 \mathrm{k}, C_{L}=50 \mathrm{pF}$ |  |  |  |  |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | 50 30 | 90 60 | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{T(H L)}, \mathrm{t}^{\text {T }}$ (LH) | Transition Time | $V_{C C}=5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 45 | 80 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 30 | 60 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF}$ |  | 75 | 140 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF}$ |  | 50 | 100 | ns |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance (Output Enabled Per Buffer) MM54C240/MM74C240 MM54C244/MM74C244 |  |  |  |  |  |
|  |  | (See Note 3) |  |  |  |  |
|  |  |  |  | 100 |  | pF |
|  |  |  |  | 100 |  | pF |
|  | (Output Disabled Per Buffer) MM54C240/MM74C240 MM54C244/MM74C244 |  |  | 10 0 |  | pF |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance (Any Input) | $V_{\text {IN }}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 10 |  | pF |
| $\mathrm{C}_{0}$ | Output Capacitance (Output Disabled) | $V_{\text {IN }}=0 V, f=1 \mathrm{MHz}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 10 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: CPD determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note, AN-90.

Typical Application


| ODA | $I A$ | $O A$ |
| :---: | :---: | :---: |
| 1 | $X$ | $Z$ |
| 1 | $x$ | $Z$ |
| 0 | 0 | 1 |
| 0 | 1 | 0 |

MM54C244/MM74C244

| ODA | IA | OA |
| :---: | :---: | :---: |
| 1 | $X$ | $Z$ |
| 1 | $X$ | $Z$ |
| 0 | 0 | 0 |
| 0 | 1 | 1 |

$$
\begin{aligned}
& 1=\text { High } \\
& 0=\text { Low } \\
& X=\text { Don't Care } \\
& z=\text { TRI-STATE }
\end{aligned}
$$

| ODB | IB | OB |
| :---: | :---: | :---: |
| 1 | $X$ | $Z$ |
| 1 | $X$ | $Z$ |
| 0 | 0 | 1 |
| 0 | 1 | 0 |


| ODB | IB | OB |
| :---: | :---: | :---: |
| 1 | $X$ | $Z$ |
| 1 | $X$ | $Z$ |
| 0 | 0 | 0 |
| 0 | 1 | 1 |

## Typical Performance Characteristics



MM54C240/MM74C240
Propagation Delay Vs. Load Capacitance


P-Channel Output Drive @ $25^{\circ} \mathrm{C}$


MM54C244/MM74C244
Propagation Delay Vs. Load Capacitance


## AC Test Circuits and Switching Time Waveforms

$t_{p d 0}, t_{\text {pd1 }}$




Note: $\mathrm{V}_{\mathrm{OH}}$ is defined as the DC output high voltage when the device is loaded with a $1 \mathrm{k} \Omega$ resistor to ground.



Note: $V_{O L}$ is defined as the DC output low voltage when the device is loaded with a $1 \mathrm{k} \Omega$ resistor to $\mathrm{V}_{\mathrm{CC}}$.

# MM54C373/MM74C373 TRI-STATE ${ }^{\circledR}$ Octal D-Type Latch MM54C374/MM74C374 TRI-STATE ${ }^{\circledR}$ Octal D-Type Flip-Flop 

## General Description

The MM54C373/MM74C373, MM54C374/MM74C374 are integrated, complementary MOS (CMOS), 8-bit storage elements with TRI-STATE ${ }^{\oplus}$ outputs. These outputs have been specially designed to drive highly capacitive loads, such as one might find when driving a bus, and to have a fan-out of 1 when driving standard TTL. When a high logic level is applied to the OUTPUT DISABLE input, all outputs go to a high impedance state, regardless of what signals are present at the other inputs and the state of the storage elements.
The MM54C373/MM74C373 is an 8-bit latch. When $\overline{\text { LATCH }}$ ENABLE is high, the Q outputs will follow the D inputs. When $\overline{\text { LATCH }} \overline{\text { ENABLE }}$ goes low, data at the $D$ inputs, which meets the set-up and hold time requirements, will be retained at the outputs until $\overline{\text { LATCH }}$ ENABLE returns high again.

The MM54C374/MM74C374 is an 8-bit, D-type, positiveedge triggered flip-flop. Data at the Dinputs, meeting the set-up and hold time requirements, is transferred to the Q outputs on positive-going transitions of the CLOCK input.
Both the MM54C373/MM74C373 and the MM54C374I MM74C374 are being assembled in 20 -pin dual-in-line packages with $0.300^{\prime \prime}$ pin centers.

## Features

- Wide supply voltage range
3.0 V to 15 V
- High noise immunity $0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.)
- Low power consumption
- TTL compatibility
fan-out of 1 driving standard TTL
- Bus driving capability
- TRI-STATE outputs
- Eight storage elements in one package
- Single CLOCKIATCH $\overline{\text { ENABLE }}$ and OUTPUT DISABLE control inputs
- 20-pin dual-in-line package with $0.300^{\prime \prime}$ centers takes half the board space of a 24-pin package


## Connection Diagrams

MM54C373/MM74C373
Dual-In-Line Package


TOP VIEW

MM54C374/MM74C374
Dual-In-Line Package


TOP VIEW

| Absolute Maximum Ratings | (Note 1 ) |
| :--- | ---: |
| Voltage at Any Pin | -0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$ |
| Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM54C373 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| MM74C373 | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Storage Temperature Range | 500 mW |
| Package Dissipation | 3 V to 15 V |
| Operating VCC Range | 18 V |
| Absolute Maximum $\mathrm{V}_{\mathrm{CC}}$ | $300^{\circ} \mathrm{C}$ |

DC Electrical Characteristics Max./min. limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{1 \times(1)}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{v} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | v |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical " 1 " Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | v |
| $\mathrm{V}_{\text {OUt(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $\mathrm{IIN(1)}^{\text {(1) }}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| IIN(0) | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| loz | TRI-STATE® Leakage Current | $\begin{aligned} & V_{C C}=15 \mathrm{~V}, V_{O}=15 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V}, V_{O}=0 \mathrm{~V} \end{aligned}$ | -1.0 | $\begin{array}{r} 0.005 \\ -0.005 \end{array}$ | 1.0 | ${ }_{\mu \mathrm{A}}^{\mu \mathrm{A}}$ |
| lcc | Supply Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| CMOS/LPTTL Interface |  |  |  |  |  |  |
| $\mathrm{V}_{1 \times(1)}$ | Logical "1" Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{array}$ | $\left.\begin{array}{\|l\|} \hline V_{c c}-1.5 \\ V_{c C}-1.5 \end{array} \right\rvert\,$ |  |  |  |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical "0" Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{array}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | v |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad I_{0}=-360 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{array}$ | $\left\|\begin{array}{l} v_{c c}-0.4 \\ v_{c c}-0.4 \end{array}\right\|$ |  |  | v |
|  |  | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, I_{0}=-1.6 \mathrm{~mA} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, I_{0}-1.6 \mathrm{~mA} \end{array}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | v |
| $V_{\text {OUT(O) }}$ | Logical "0" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad I_{\mathrm{O}}=1.6 \mathrm{~mA} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, I_{\mathrm{O}}=1.6 \mathrm{~mA} \end{array}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | v |
| Output Drive (Short Circuit Current) |  |  |  |  |  |  |
| Isource | Output Source Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \quad(\text { Note 4) } \end{aligned}$ | -12 | -24 |  | mA |
| Isource | Output Source Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{\text {Out }}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \quad(\text { Note 4) } \end{aligned}$ | -24 | -48 |  | mA |
| ISINK | Output Sink Current ( N -Channel) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \quad V_{\text {OUT }}=V_{C C} \\ & T_{A}=25^{\circ} \mathrm{C} \quad(\text { Note 4) } \end{aligned}$ | 6.0 | 12 |  | mA |
| $I_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\text {Out }}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \quad(\text { Note 4) } \end{aligned}$ | 24 | 48 |  | mA |

## AC Electrical Characteristics

MM54C373/MM74C373 $T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise noted.

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {pd } 0}, t_{\text {pd } 1}$ | Propagation Delay, LATCH/ENABLE to Output | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & V_{C C}=10 \mathrm{~V}, C_{\mathrm{L}}=50 \mathrm{pF} \\ & V_{C C}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF} \\ & V_{C C}=10 \mathrm{~V}, C_{\mathrm{L}}=150 \mathrm{pF} \end{aligned}$ |  | $\begin{gathered} 165 \\ 70 \\ 195 \\ 85 \end{gathered}$ | $\begin{aligned} & 330 \\ & 140 \\ & 390 \\ & 170 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd0 }}, t_{\text {pd } 1}$ | Propagation Delay Data In to Output | $\begin{aligned} & \hline \text { LATCH ENABLE }=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF} \end{aligned}$ |  | $\begin{gathered} 155 \\ 70 \\ 185 \\ 85 \end{gathered}$ | $\begin{aligned} & 310 \\ & 140 \\ & 370 \\ & 170 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {SET-UP }}$ | Minimum Set-Up Time Data In to CLOCK/LATCH ENABLE | $\begin{aligned} & t_{\mathrm{HOLD}}=0 \mathrm{~ns} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 70 \\ & 35 \end{aligned}$ | $\begin{aligned} & 140 \\ & 70 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $f_{\text {MAX }}$ | Maximum $\overline{\text { LATCH ENABLE }}$ Frequency | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.3 \\ & 4.5 \end{aligned}$ | $\begin{aligned} & 6.7 \\ & 9.0 \end{aligned}$ |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $t_{\text {PWH }}$ | Minimum $\overline{\text { LATCH ENABLE Pulse }}$ Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 75 \\ & 55 \end{aligned}$ | $\begin{aligned} & 150 \\ & 110 \end{aligned}$ | ns <br> ns |
| $t_{r}, t_{f}$ | Maximum $\overline{\text { LATCH ENABLE }}$ Rise and Fall Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & \text { NA } \\ & \text { NA } \end{aligned}$ |  | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \end{aligned}$ |
| $t_{1 H}, t_{0 H}$ | Propagation Delay OUTPUT DISABLE to High Impedance State (from a Logic Level) | $\begin{aligned} & R_{L}=10 \mathrm{k}, C_{L}=50 \mathrm{pF} \\ & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 105 \\ 60 \end{gathered}$ | $\begin{aligned} & 210 \\ & 120 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{H 1}, t_{\text {H0 }}$ | Propagation Delay OUTPUT DISABLE to Logic Level (from High Impedance State) | $\begin{aligned} & R_{L}=10 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 105 \\ 45 \end{gathered}$ | $\begin{aligned} & 210 \\ & 90 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {THL }}, \mathrm{t}_{\text {TLH }}$ | Transition Time | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}} 150 \mathrm{pF} \end{aligned}$ | - | $\begin{gathered} 65 \\ 35 \\ 110 \\ 70 \end{gathered}$ | $\begin{gathered} 130 \\ 70 \\ 220 \\ 140 \end{gathered}$ | ns <br> ns <br> ns <br> ns |
| $\mathrm{C}_{\text {LE }}$ | Input Capacitance | $\overline{\mathrm{LE}}$ Input (Note 2) |  | 7.5 | 10 | pF |
| $\mathrm{C}_{\text {OD }}$ | Input Capacitance | OUTPUT DISABLE Input (Note 2) |  | 7.5 | 10 | pF |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Any Other Input (Note 2) |  | 5.0 | 7.5 | pF |
| $\mathrm{C}_{\text {OUT }}$ | Output Capacitance | High Impedance State (Note 2) |  | 10 | 15 | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | Per Package (Note 3) |  | 200 |  | pF |

## AC Electrical Characteristics

MM54C374/MM74C374 $T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay, CLOCK to Output | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF} \end{aligned}$ |  | $\begin{gathered} 150 \\ 65 \\ 180 \\ 80 \end{gathered}$ | $\begin{aligned} & 300 \\ & 130 \\ & 360 \\ & 160 \end{aligned}$ | ns ns ns ns |
| $\mathrm{t}_{\text {SET-UP }}$ | Minimum Set-Up Time Data In to CLOCKILATCH ENABLE | $\begin{aligned} & \mathrm{t}_{\mathrm{HOLD}}=0 \mathrm{~ns} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | 70 35 | $\begin{aligned} & 140 \\ & 70 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| ${ }_{\text {tpwh }} \mathrm{t}_{\text {PWL }}$ | Minimum CLOCK Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 70 \\ & 50 \end{aligned}$ | $\begin{aligned} & 140 \\ & 100 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{f}_{\text {MAX }}$ | Maximum CLOCK Frequency | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 5.0 \end{aligned}$ | $\begin{aligned} & 7.0 \\ & 10 \end{aligned}$ |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $\mathrm{t}_{1 \mathrm{H}}, \mathrm{t}_{\mathrm{OH}}$ | Propagation Delay OUTPUT DISABLE to High Impedance State (from a Logic Level) | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | ${ }_{60} 105$ | 210 120 | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{H} 1}, \mathrm{t}_{\mathrm{HO}}$ | Propagation Delay OUTPUT DISABLE to Logic Level (from High Impedance State) | $\begin{aligned} & R_{\mathrm{L}}=10 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 105 \\ & 45 \end{aligned}$ | $\begin{aligned} & 210 \\ & 90 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| ${ }^{\text {THLL }}$, $\mathrm{t}_{\text {TLH }}$ | Transition Time | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{CCC}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF} \end{aligned}$ |  | $\begin{gathered} 65 \\ 35 \\ 110 \\ 70 \end{gathered}$ | $\begin{aligned} & 130 \\ & 70 \\ & 220 \\ & 140 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}$ | Maximum CLOCK Rise and Fall Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 15 \\ & 5.0 \end{aligned}$ | $\begin{array}{\|l} >2000 \\ >2000 \end{array}$ |  | ${ }_{\mu \mathrm{S}}^{\mu \mathrm{S}}$ |
| $\mathrm{C}_{\text {CLK }}$ | Input Capacitance | CLOCK Input (Note 2) |  | 7.5 | 10 | pF |
| $\mathrm{C}_{\text {OD }}$ | Input Capacitance | OUTPUT DISABLE Input (Note 2) |  | 7.5 | 10 | pF |
| $\mathrm{Cin}_{\text {I }}$ | Input Capacitance | Any Other Input (Note 2) |  | 5.0 | 7.5 | pF |
| $\mathrm{Cout}^{\text {coin }}$ | Output Capacitance | High Impedance State (Note 2) |  | 10 | 15 | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | Per Package (Note 3) |  | 250 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\mathrm{PD}}$ determines the no load $A C$ power consumption of any CMOS device. For complete explanation see $54 \mathrm{C} / 74 \mathrm{C}$ Family Characteristics application note AN-90.
Note 4: These are peak output current capabilities. Continuous output current is rated at 12 mA max.

Typical Performance Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$


MM54C373/MM74C373, MM54C374/MM74C374
Change in Propagation Delay per pF of Load Capacitance ( $\Delta \mathrm{tPD} / \mathrm{pF}$ ) vs Power Supply Voltage


## Truth Tables

MM54C373/MM74C373

| OUTPUT <br> DISABLE | $\overline{\text { LATCH }}$ | D | Q |
| :---: | :---: | :---: | :---: |
| L | H | H | H |
| L | $H$ | L | L |
| L | L | X | Q |
| H | X | X | $\mathrm{Hi}-\mathrm{Z}$ |

## Typical Applications

Data Bus Interfacing Element

| OUTPUT <br> DISABLE | CLOCK | D | $\mathbf{Q}$ |
| :---: | :---: | :---: | :---: |
| $L$ | - | $H$ | $H$ |
| $L$ | - | $L$ | $L$ |
| L | L | $X$ | $Q$ |
| L | $H$ | $X$ | $Q$ |
| $H$ | $X$ | $X$ | $\mathrm{Hi}-\mathrm{Z}$ |



MM54C373/MM74C373, MM54C374/MM74C374 Output Sink Current vs VOUT


MM54C374/MM74C374
Propagation Delay, CLOCK to Output vs Load Capacitance


MM54C373/MM74C373, MM54C374/MM74C374 Output Source Current vs VCC - VOUT

$L=$ low logic level
$H=$ high logic level
X = irrelevant

- $=$ low to high logic level transition
$Q=$ preexisting output level
$\mathrm{Hi}-\mathrm{Z}=$ high impedance output state


Simple, Latching, Octal, LED Indicator Driver with Blanking For Use As Data Display, Bus Monitor, $\mu$ P Front Panel Display, Etc.


MM54C374/MM74C374 (1 of 8 Flip-Flops)




TRI-STATE ${ }^{\circledR}$ Test Circuits and Timing Diagrams
t1H, tH1

$\mathbf{t O H}_{\mathbf{O}} \mathbf{t} \mathbf{H O}$

$t 1 H, C_{L}=5 p F$

$\mathrm{t}_{\mathrm{OH}}, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}$

$\mathrm{t}_{\mathrm{H}} 1, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$

$t \mathrm{HO}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$


Switching Time Waveforms

MM54C373/MM74C373


OUTPUT DISABLE $=$ GND MM54C374/MM74C374


OUTPUT DISABLE $=$ GND

# MM70C95/MM80C95, MM70C97/MM80C97 TRI-STATE ${ }^{\circledR}$ Hex Buffers MM70C96/MM80C96, MM70C98/MM80C98 TRI-STATE ${ }^{\circledR}$ Hex Inverters 

## General Description

These gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N - and P-channel enhancement mode transistors. The MM70C95/MM80C95 and the MM70C97/MM80C97 convert CMOS or TTL outputs to TRI-STATE outputs with no logic inversion, the MM70C96/MM80C96 and the MM70C98/MM80C98 provide the logical opposite of the input signal. The MM70C95/MM80C95 and the MM70C96/MM80C96 have common TRI-STATE controls for all six devices. The MM70C97/MM80C97 and the MM70C98/MM80C98 have two TRI-STATE controls; one for two devices and one for the other four devices. Inputs are protected from damage due to static discharge by diode clamps to $\mathrm{V}_{\mathrm{CC}}$ and GND.
Features- Wide supply voltage range- Guaranteed noise margin3.0 V to 15 V- High noise immunity- TTL compatible
Applications

- Bus drivers

Typical propagation delay into 150 pF load is 40 ns .

MM70C95/MM80C95


TOP VIEW

## MM70C97/MM80C97



MM70C96/MM80C96

top view

## MM70C98/MM80C98



| Absolute Maximum Ratings | (Note 1$)$ |
| :--- | ---: |
| Voltage at Any Pin | -0.3 V to V CC +0.3 V |
| Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM 70 CXX | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| MM80CXX | $-65^{\circ} \mathrm{C}$ to $+10^{\circ} \mathrm{C}$ |
| Storage Temperature Range | 500 mW |
| Package Dissipation | 18 V |
| Power Supply Voltage $\left(V_{\mathrm{CC}}\right)$ | $300^{\circ} \mathrm{C}$ |

## DC Electrical Characteristics

Max./min. limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {IN(0) }}$ | Logical "0' Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| VOUT(1) | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {OUT }}$ (0) | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $I_{\text {IN(1) }}$ | Logical "1" Input Current | $V_{C C}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $1 \mathrm{IN}(0)$ | Logical "0" Input Current |  | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| lout | Output Current in High Impedance State | $\begin{aligned} & V_{C C}=15 \mathrm{~V}, V_{O}=15 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V}, V_{O}=0 \mathrm{~V} \end{aligned}$ | -1.0 | $\begin{array}{r} 0.005 \\ -0.005 \end{array}$ | 1.0 | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |
| $\mathrm{I}_{\mathrm{CC}}$ | Supply Current | $V_{C C}=15 \mathrm{~V}$ |  | 0.01 | 15 | $\mu \mathrm{A}$ |
| TTL Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\operatorname{IN}(1)}$ | Logical "1" Input Voltage | $\begin{array}{ll} 70 \mathrm{C} & V_{C C}=4.5 \mathrm{~V} \\ 80 \mathrm{C} & V_{C C}=4.75 \mathrm{~V} \end{array}$ | $\begin{aligned} & V_{C C}-1.5 \\ & V_{C C}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical "0" Input Voltage | $\begin{array}{ll} 70 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ 80 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{array}$ |  | , | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & 70 \mathrm{C}^{-} \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-1.6 \mathrm{~mA} \\ & 80 \mathrm{C} \end{aligned} \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-1.6 \mathrm{~mA}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical '0" Output Voltage | $\begin{array}{ll} 70 \mathrm{C} & V_{C C}=4.5 \mathrm{~V}, I_{O}=1.6 \mathrm{~mA} \\ 80 \mathrm{C} & V_{C C}=4.75 \mathrm{~V}, I_{\mathrm{O}}=1.6 \mathrm{~mA} \end{array}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Output Drive (Short Circuit Current) |  |  |  |  |  |  |
| $I_{\text {SOURCE }}$ | Output Source Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{I N(1)}=5.0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \end{aligned}$ | -4.35 |  |  | mA |
| $I_{\text {SOURCE }}$ | Output Source Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, \mathrm{~V}_{\text {IN(1) }}=10 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \end{aligned}$ | -20 |  |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {IN(0) }}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 4.35 |  |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N(0)}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, V_{O U T}=V_{C C} \end{aligned}$ | 20 |  |  | mA |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note AN-90.

AC Electrical Characteristics $T_{A}=25^{\circ} C, C_{L}=50 \mathrm{pF}$, unless otherwise noted.

| Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{p d 0}, t_{p d 1}$ Propagation Delay Time to a Logical " 0 " or Logical "1" from Data Input to Output MM70C95/MM80C95, MM70C97/MM80C97 MM70C96/MM80C96, MM70C98/MM80C98 | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 60 \\ & 25 \\ & 70 \\ & 35 \end{aligned}$ | $\begin{gathered} 100 \\ 40 \\ 150 \\ 75 \end{gathered}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{p d 0}, t_{p d 1}$ Propagation Delay Time to a Logical " 0 " or Logical "1" from Data Input to Output MM70C95/MM80C95, MM70C97/MM80C97 MM70C96/MM80C96, MM70C98/MM80C98 | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, C_{\mathrm{L}}=150 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF} \end{aligned}$ |  | $\begin{aligned} & 85 \\ & 40 \\ & 95 \\ & 45 \end{aligned}$ | $\begin{gathered} 160 \\ 80 \\ 210 \\ 110 \end{gathered}$ | ns <br> ns <br> ns ns |
| $\mathbf{t}_{1 \mathrm{H}}, \mathrm{t}_{\mathrm{OH}}$ Delay from Disable Input to High Impedance State, (from Logical " 1 " or Logical " 0 ") <br> MM70C95/MM80C95 <br> MM70C96/MM80C96 <br> MM70C97/MM80C97 <br> MM70C98/MM80C98 | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=5.0 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 80 \\ 50 \\ 100 \\ 70 \\ 70 \\ 50 \\ 90 \\ 70 \end{gathered}$ | $\begin{gathered} 135 \\ 90 \\ 180 \\ 125 \\ 125 \\ 90 \\ 170 \\ 125 \end{gathered}$ |  |
| $\mathrm{t}_{\mathrm{H} 1}, \mathrm{t}_{\mathrm{H} 0}$ Delay from Disable Input to Logical " 1 " Level (from High Impedance State) <br> MM70C95/MM80C95 <br> MM70C96/MM80C96 <br> MM70C97/MM80C97 <br> MM70C98/MM80C98 | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 120 \\ 50 \\ 130 \\ 60 \\ 95 \\ 40 \\ 120 \\ 50 \end{gathered}$ | $\begin{gathered} 200 \\ 90 \\ 225 \\ 110 \\ 175 \\ 80 \\ 200 \\ 90 \end{gathered}$ |  |
| $\mathrm{C}_{\text {IN }} \quad$ Input Capacitance | Any Input (Note 2) |  | 5.0 |  | pF |
| Cout Output Capacitance TRI-STATE | Any Output (Note 2) |  | 11 |  | pF |
| $\mathrm{C}_{\text {PD }} \quad$ Power Dissipation Capacitance | (Note 3) |  | 60 |  | pF |

## Truth Table

MM70C95/MM80C95

| DISABLE <br> DIS $_{\mathbf{1}}$ | INPUT $^{2}$ <br> DIS $_{\mathbf{2}}$ | INPUT | OUTPUT |
| :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | 0 |
| 0 | 0 | 1 | 1 |
| 0 | 1 | X | $\mathrm{H}-\mathrm{z}$ |
| 1 | 0 | X | $\mathrm{H} \cdot \mathrm{z}$ |
| 1 | 1 | X | $\mathrm{H}-\mathrm{z}$ |

MM70C97/MM80C97

| DISABLE $^{\text {DIS }_{\mathbf{4}}}$ | INPUT <br> DIS $_{\mathbf{2}}$ | INPUT | OUTPUT |
| :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | 0 |
| 0 | 0 | 1 | 1 |
| X | 1 | X | $\mathrm{H} \cdot \mathrm{z}^{*}$ |
| 1 | X | X | $\mathrm{H}-\mathrm{z}^{* *}$ |

MM70C98/MM80C98

| DISABLE <br> DIS $_{\mathbf{4}}$ | INPUT <br> DIS $_{\mathbf{2}}$ | INPUT | OUTPUT |
| :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | 1 |
| 0 | 0 | 1 | 0 |
| $X$ | 1 | X | $\mathrm{H} \cdot \mathrm{z}^{*}$ |
| 1 | X | X | $\mathrm{H} \cdot \mathrm{z}^{* *}$ |

[^4]| DISABLE <br> DIS $_{\mathbf{1}}$ | INPUT <br> DIS $_{\mathbf{2}}$ | INPUT | OUTPUT |
| :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | 1 |
| 0 | 0 | 1 | 0 |
| 0 | 1 | X | $\mathrm{H} \cdot \mathrm{z}$ |
| 1 | 0 | X | $\mathrm{H} \cdot \mathrm{z}$ |
| 1 | 1 | X | $\mathrm{H} \cdot \mathrm{z}$ |

## Typical Performance Characteristics




## Schematic Diagram

MM70C97/MM80C97 TRI-STATE



P-Channel Output Drive @ $25^{\circ} \mathrm{C}$


MM70C96/MM80C96 TRI-STATE


MM70C98/MM80C98 TRI-STATE


## AC Test Circuit and Switching Time Waveforms






## MM78C29/MM88C29 Quad Single-Ended Line Driver MM78C30/MM88C30 Dual Differential Line Driver

## General Description

The MM78C30/MM88C30 is a dual differential line driver that also performs the dual four-input NAND or dual fourinput AND function. The absence of a clamp diode to $V_{C C}$ in the input protection circuitry of the MM78C30/MM88C30 allows a CMOS user to interface systems operating at different voltage levels. Thus, a CMOS digital signal source can operate at a $\mathrm{V}_{\mathrm{CC}}$ voltage greater than the $\mathrm{V}_{\mathrm{CC}}$ voltage of the MM78C30 line driver. The differential output of the MM78C30/MM88C30 eliminates ground-loop errors.

The MM78C29/MM88C29 is a non-inverting single-wire transmission line driver. Since the output ON resistance is a low $20 \Omega$ typ., the device can be used to drive lamps, relays, solenoids, and clock lines, besides driving data lines.

## Features

| - Wide supply voltage range | 3.0 V to 15 V |
| :--- | ---: |
| - High noise immunity | $0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.) |
| - Low output ON resistance | $20 \Omega$ (typ.) |

## Logic and Connection Diagrams



| Absolute Maximum Ratings（Note 1） |  |
| :--- | ---: |
| Voltage at Any Pin（Note 1） | -0.3 V to $\mathrm{V}_{\mathrm{CC}}+16 \mathrm{~V}$ |
| Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM 78 C 299 MM 78 C 30 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| MM88C29／MM88C30 | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Storage Temperature | 500 mW |
| Package Dissipation | 3.0 V to 15 V |


| Absolute Maximum $V_{C C}$ | 18 V |
| :--- | :---: |
| Average Current at Output |  |
| MM78C30／MM88C30 | 50 mA |
| MM78C29／MM88C29 | 25 mA |
| Maximum Junction Temperature， $\mathrm{T}_{\mathrm{j}}$ | $150^{\circ} \mathrm{C}$ |
| Lead Temperature（Soldering， 10 sec. ） | $300^{\circ} \mathrm{C}$ |

DC Electrical Characteristics Max．／min．limits apply across temperature range unless otherwise noted．


DC Electrical Characteristics


AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {pd }}$ | Propagation Delay Time to Logical " 1 " or " 0 " MM78C29/MM88C29 | $\begin{aligned} & \text { (See Figure 2) } \\ & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | 80 35 | $\begin{aligned} & 200 \\ & 100 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
|  | MM78C30/MM88C30 | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 110 \\ 50 \end{gathered}$ | $\begin{aligned} & 350 \\ & 150 \end{aligned}$ | ns <br> ns |
| $t_{p d}$ | Differential Propagation Delay Time to Logical " 1 " or "0" MM78C30/MM88C30 | $\mathrm{R}_{\mathrm{L}}=100 \Omega, \mathrm{C}_{\mathrm{L}}=5000 \mathrm{pF}$ <br> (See Figure 1) $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 400 \\ & 150 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{ClN}_{\text {IN }}$ | Input Capacitance MM78C29/MM88C29 MM78C30/MM88C30 | (Note 3) <br> (Note 3) |  | $\begin{aligned} & 5.0 \\ & 5.0 \end{aligned}$ |  | $\begin{aligned} & \mathrm{pF} \\ & \mathrm{pF} \end{aligned}$ |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance MM78C29/MM88C29 MM78C30/MM88C30 | (Note 3) <br> (Note 3) |  | $\begin{aligned} & 150 \\ & 200 \end{aligned}$ |  | $\begin{aligned} & \mathrm{pF} \\ & \mathrm{pF} \end{aligned}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $C_{P D}$ determines the no load $A C$ power consumption of any CMOS device. For complete explanation see $54 C / 74 C$ Family Characteristics application note AN-90.

## Typical Performance Characteristics



## AC Test Circuits



FIGURE 1.


FIGURE 2.

Digital Data Transmission


Typical Data Rate vs Transmission Line Length


Note 1: The transmission line used was \#22 gauge unshielded twisted pair (40k termination).
Note 2: The curves generated assume that both drivers are driving equal lines, and that the maximum power is $500 \mathrm{~mW} /$ package.

## Section 2

## MM54C9XX/MM74C9XX Special Function/LSI Devices

$\qquad$

# MM54C901/MM74C901 Hex Inverting TTL Buffer MM54C902/MM74C902 Hex Non-Inverting TTL Buffer MM54C903/MM74C903 Hex Inverting CMOS Buffer MM54C904/MM74C904 Hex Non-Inverting CMOS Buffer 

## General Description

These hex buffers employ complementary MOS to achieve wide supply operating range, low power consumption, and high noise immunity. These buffers provide direct interface from PMOS into CMOS or TTL and direct interface from CMOS to TTL or CMOS operating at a reduced $V_{C C}$ supply. For specific applications see MOS Brief 18 in the back of this catalog.

## Features

| - Wide supply voltage range | 3.0 V to 15 V |
| :--- | ---: |
| - Guaranteed noise margin | 1.0 V |
| - High noise immunity | $0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.) |
| - TTL compatibility | fan out of 2 |
|  | driving standard TTL |

## Connection and Logic Diagrams

MM54C901/MM74C901
MM54C903/MM74C903


TOP VIEW

MM54C901/MM74C901
CMOS to TTL Inverting Buffer


MM54C902/MM74C902 CMOS to TTL Buffer


MM54C902/MM74C902
MM54C904/MM74C904


MM54C903/MM74C903
PMOS to TTL or CMOS Inverting Buffer


MM54C904/MM74C904 PMOS to TTL or CMOS Buffer


Absolute Maximum Ratings (Note 1)

Voltage at Any Pin
Voltage at any Input Pin MM54C901/MM74C901 MM54C902/MM74C902 MM54C903/MM74C903 MM54C904/MM74C904
Storage Temperature Range
Package Dissipation
-0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
-0.3 V to +15 V
-0.3 V to +15 V
$V_{C C}-17 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
$\mathrm{V}_{\mathrm{CC}}-17 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW

Operating Temperature Range MM54C901, MM54C902,
MM54C903, MM54C904 $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
MM74C901, MM74C902, MM74C903, MM74C904
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ 3.0 V to 15 V

Absolute Maximum $\mathrm{V}_{\mathrm{Cc}}$
Lead Temperature (Soldering, 10 sec.)
$300^{\circ} \mathrm{C}$

DC Electrical Characteristics Max.min. limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | V |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | V |
| $\mathrm{V}_{\text {OUT }}(0)$ | Logical "0" Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{I}_{\mathbf{N}(1)}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $1 \mathrm{IN}(0)$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{CC}}$ | Supply Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 0.05 | 15 | $\mu \mathrm{A}$ |
| TTL to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\operatorname{IN}(1)}$ | Logical "1" Input Voltage | $\begin{array}{\|ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V} \end{array}$ | $\begin{aligned} & V_{C C}-1.5 \\ & V_{C C}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V} \end{array}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| CMOS to TTL |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IN}(1)}$ | Logical " 1 " Input Voltage MM54C901, MM54C903 MM54C902, MM54C904 MM74C901, MM74C903 MM74C902, MM74C904 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 4.0 \\ V_{C C}-1.5 \\ 4.25 \\ V_{C C}-1.5 \end{gathered}$ |  |  | $\begin{aligned} & V \\ & V \\ & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical " 0 "' Input Voltage <br> MM54C901, MM54C903 <br> MM54C902, MM54C904 <br> MM74C901, MM74C903 <br> MM74C902, MM74C904 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | 1.0 1.5 1.0 1.5 | $\begin{aligned} & V \\ & V \\ & V \\ & V \end{aligned}$ |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-800 \mu \mathrm{~A} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-800 \mu \mathrm{~A} \end{array}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {OUT(0) }}$ | Logical " 0 " Output Voltage MM54C901, MM54C903 MM54C902, MM54C904 MM74C901, MM74C903 MM74C902, MM74C904 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{O}}=2.6 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=3.2 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=2.6 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=3.2 \mathrm{~mA} \end{aligned}$ |  |  | 0.4 0.4 0.4 0.4 | $\begin{aligned} & V \\ & V \\ & V \\ & V \end{aligned}$ |

## Output Drive (See 54C/74C Family Characteristics Data Sheet) (Short Circuit Current) (MM54C901/MM74C901, MM54C903/MM74C903)

| Isource | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V} \end{aligned}$ | -5.0 |  | mA |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{\text {OUT }}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V} \end{aligned}$ | -20 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{O U T}=V_{C C} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{I N}=V_{C C} \end{aligned}$ | 9.0 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=0.4 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {IN }}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 3.8 |  | mA |

## DC Electrical Characteristics (cont'd)

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Output Drive (See 54C/74C Family Characteristics Data Sheet) (Short Circuit Current) (MM54C902/MM74C902, MM54C902/MM74C902) |  |  |  |  |  |  |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | -5.0 |  |  | mA |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{O U T}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {IN }}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | -20 |  |  | mA |
| $I_{\text {SINK }}$ | Output Sink Current ( N -Channel) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{O U T}=V_{C C} \\ & T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{I N}=0 \mathrm{~V} \end{aligned}$ | 9.0 |  |  | mA |
| ISINK | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0.4 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V} \end{aligned}$ | 3.8 |  |  | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| MM54C901/MM74C901, MM54C903/MM74C903 |  |  |  |  |  |  |
| $\mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Time to a Logical " 1 " | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | - | 38 | 70 30 | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd0 }}$ | Propagation Delay Time to a Logical " 0 " | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | 21 13 | $\begin{aligned} & 35 \\ & 20 \end{aligned}$ | ns |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance | Any Input (Note 2) |  | 14 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacity | (Note 3) Per Buffer |  | 30 |  | pF |
| MM54C902/MM74C902, MM54C904/MM74C904 |  |  |  |  |  |  |
| $\mathrm{t}_{\text {pd1 }}$ | Propagation Delay Time to a Logical "1" | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | 57 27 | 90 40 | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pd0 }}$ | Propagation Delay Time to a Logical " 0 " | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | 54 25 | $\begin{aligned} & 90 \\ & 40 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance | Any Input (Note 2) |  | 5.0 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacity | (Note 3) Per Buffer |  | 50 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\mathrm{PD}}$ determines the no load $A C$ power consumption of any CMOS device. For complete explanation see $54 \mathrm{C} / 74 \mathrm{C}$ Farnily Characteristics application note AN-90.

## Typical Applications



## AC Test Circuit and Switching Time Waveform



Note: Delays measured with input $t_{r}, t_{f}=20$ ns.

CMOS to CMOS


Typical Propagation Delay to a Logical " 0 " for the MM54C901/ MM74C901 and MM54C903/ MM74C903

$C_{L}(\mathrm{pF})$

Typical Propagation Delay to a Logical "0" for the MM54C902/ MM74C902 and MM54C904/ MM74C904


$$
C_{L}(p F)
$$

Typical Propagation Delay to a Logical " 1 " for the MM54C901/
MM74C901 and MM54C903/
MM74C903


$$
c_{L}(p F)
$$

Typical Propagation Delay to a Logical " 1 " for the MM54C902/ MM74C902 and MM54C904/ MM74C904

$\mathrm{C}_{\mathrm{L}}(\mathrm{pF})$

## MM54C905/MM74C905 12-Bit Successive Approximation Register

## General Description

The MM54C905/MM74C905 CMOS 12-bit successive approximation register contains all the digit control and storage necessary for successive approximation analog-to-digital conversion. Because of the unique capability of CMOS to switch to each supply rail without any offset voltage, it can also be used in digital systems as the control and storage element in repetitive routines.

## Features

- Wide supply voltage range
3.0 V to 15 V
- Guaranteed noise margin
1.0 V
- High noise immunity
- Low power TTL compatibility
$0.45 \mathrm{~V}_{\mathrm{cc}}$ typ
fan out of 2 driving 74L
- Provision for register extension or truncation
- Operates in START/STOP or continuous conversion mode
- Drive ladder switches directly. For 10 bits or less with $50 \mathrm{k} / 100 \mathrm{k}$ R/2R ladder network


## Connection Diagram



## Truth Table

| TIME | INPUTS |  |  | OUTPUTS |  |  |  |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{n}$ | D | $\bar{S}$ | $\overline{\mathrm{E}}$ | D0 | Q11 | Q10 | Q9 | Q8 | Q7 | Q6 | Q5 | Q4 | Q3 | Q2 | Q1 | Q0 | $\overline{\mathrm{CC}}$ |
| 0 | $X$ | L | L | $x$ | X | X | X | X | X | X | X | X | X | X | X | X | X |
| 1 | D11 | H | L | X | L | H | H | H | H | H | H | H | H | H | H | H | H |
| 2 | D10 | H | L | D11 | D11 | L | H | H | H | H | H | H | H | H | H | H | H |
| 3 | D9 | H | L | D10 | D11 | D10 | L | H | H | H | H | H | H | H | H | H | H |
| 4 | D8 | H | L | D9 | D11 | D10 | D9 | L | H | H | H | H | H | H | H | H | H |
| 5 | D7 | H | L | D8 | D11 | D10 | D9 | D8 | L | H | H | H | H | H | H | H | H |
| 6 | D6 | H | L | D7 | D11 | D10 | D9 | D8 | D7 | L | H | H | H | H | H | H | H |
| 7 | D5 | H | L | D6 | D11 | D10 | D9 | D8 | D7 | D6 | L | H | H | H | H | H | H |
| 8 | D4 | H | $L$ | D5 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | L | H | H | H | H | H |
| 9 | D3 | H | L | D4 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | L | H | H | H | H |
| 10 | D2 | H | L | D3 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | L | H | H | H |
| 11 | D1 | H | L | D2 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | L | H | H |
| 12 | DO | H | L | D1 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | L | H |
| 13 | $x$ | H | L. | D0 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 | L |
| 14 | $x$ | X | L | $x$ | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | DO | L |
|  | $x$ | X | H | $x$ | H | NC | NC | NC | NC | NC | NC | NC | NC | NC | NC | NC | NC |

$H=$ Hıgh level
$L$ = Low level
X = Don't care
$\mathrm{NC}=$ No change

| Absolute Maximum Ratings (Note 1) |  |
| :--- | ---: |
| Voltage at Any Pin | -0.3 V to $\mathrm{V} \mathrm{CC}+0.3 \mathrm{~V}$ |
| Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM54C905 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| MM74C95 | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Storage Temperature Range | 500 mW |
| Package Dissipation | 3.0 V to 15 V |
| Operating $\mathrm{V}_{\mathrm{CC}}$ Range | 16 V |
| Absolute Maximum $\mathrm{V}_{\mathrm{CC}}$ | $300^{\circ} \mathrm{C}$ |

## DC Electrical Characteristics

Min/max limits apply across temperature range unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\mathbf{N ( 1 )}}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{v} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{c \mathrm{cc}}=5.0 \mathrm{~V} \\ & V_{\mathrm{cc}}=10 \mathrm{~V} \end{aligned}$ |  |  | 1.5 2.0 | v |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | v |
| $V_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\stackrel{v}{v}$ |
| $\mathrm{I}_{1 \times(1)}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{1 \times(0)}$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| lcc | Supply Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| CMOS/LPTTL Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical " 1 " Input Voltage MM54C905 MM74C905 | $\begin{aligned} & \mathrm{V}_{\mathrm{cC}}=4.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{cC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & V_{C C}-1.5 \\ & V_{C C}-1.5 \end{aligned}$ |  |  | V |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical " 0 " Input Voltage MM54C905 MM74C905 | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \\ & V_{C C}=4.75 \mathrm{~V} \end{aligned}$ |  |  | 0.8 0.8 | v |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical " 1 " Output Voltage MM54C905 MM74C905 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | V |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical "0" Output Voltage MM54C905 MM74C905 | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V}, I_{\mathrm{O}}=360 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \\ & \hline \end{aligned}$ |  |  | 0.4 0.4 | v |


| Output Drive (See 54C/74C Family Characteristics Data Sheet) |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ISOURCE | Output Source Current (P-Channel) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{\text {OUT }}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | -1.75 | -3.3 |  | mA |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{O U T}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | -8.0 | -15 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current ( N -Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 1.75 | 3.6 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{O U T}=V_{C C} \\ & T_{A}=25^{\circ} \mathrm{C} \\ & V_{C C}=10 \mathrm{~V} \pm 5 \% \end{aligned}$ | 8.0 | 16 |  | mA |
| R Source | Q11-Q0 Outputs | $\begin{aligned} & \mathrm{V}_{\text {OUT }}=\mathrm{V}_{\mathrm{CC}}-0.3 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 150 |  | 350 | $\Omega$ |
| $\mathrm{R}_{\text {SINK }}$ |  | $\begin{aligned} & V_{C C}=10 \mathrm{~V} \pm 5 \% \\ & V_{\text {OUT }}=0.3 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | 80 |  | 230 | $\Omega$ |

AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Delay Time from Clock Input to Outputs (Q0-Q11) ( $\left.\mathrm{t}_{\mathrm{pd}(\mathrm{Q}}\right)$ ) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} 200 \\ 80 \end{array}$ | $\begin{aligned} & 350 \\ & 150 \end{aligned}$ | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Delay Time from Clock Input to $\mathrm{D}_{\mathrm{O}}\left(\mathrm{t}_{\mathrm{pd}\left(\mathrm{D}_{0}\right)}\right)$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} 180 \\ 70 \end{array}$ | $\begin{aligned} & 325 \\ & 125 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {pd }}$ | Propagation Delay Time from Register Enable (E) to Output (Q11) $\left(\mathrm{t}_{\mathrm{pd}(\mathrm{E})}\right)$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} 190 \\ 75 \end{array}$ | $\begin{aligned} & 350 \\ & 150 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Delay Time from Clock to CC ( $\left.\mathrm{t}_{\mathrm{pd}(\mathrm{CC})}\right)$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} 190 \\ 75 \end{array}$ | $\begin{aligned} & 350 \\ & 0.50 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{s}$ | Data Input Set-Up Time | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 80 \\ & 30 \end{aligned}$ |  |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{s}$ | Start Input Set-Up Time | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 80 \\ & 30 \end{aligned}$ |  |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {w }}$ | Minimum Clock Pulse Width | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 250 \\ & 100 \end{aligned}$ | $\begin{array}{r} 125 \\ 50 \end{array}$ |  | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{r}, t_{f}$ | Maximum Clock Rise and Fall Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 15 \\ & 5.0 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~s} \end{aligned}$ |
| $f_{\text {max }}$ | Maximum Clock Frequency | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 2.0 \\ & 5.0 \end{aligned}$ | $\begin{array}{r} 4.0 \\ 10 \end{array}$ |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $\mathrm{C}_{\mathrm{CK}}$ | Clock Input Capacitance | Clock Input (Note 2) |  | 10 |  | pF |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Any other Input (Note 2) |  | 5 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 3) |  | 100 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by perindic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note - AN-90.

## Typical Performance Characteristics



Timing Diagram


Switching Time Waveforms


## USER NOTES FOR A/D CONVERSION

The register can be used with either current switches that require a low voltage level to turn the switch ON or current switches that require a high voltage level to turn the switch ON. If current switches are used which turn ON with a low logic level, the resulting digit output from the register is active low. That is, a logic " 1 " is represented as a low voltage level. If current switches are used which turn ON with a high logic level, the resulting digit output is active high. A logic " 1 " is represented as a high voltage level.

For a maximum error of $\pm 1 / 2$ LSB, the comparator must be biased. If current switches that require a high voltage level to turn ON are used, the comparator should be biased $+1 / 2$ LSB and if the current switches require a low logic level to turn ON, then the comparator must be biased -1/2 LSB.

The register can be used to perform 2's complement conversion by offsetting the comparator one half full
range $+1 / 2$ LSB and using the complement of the MSB Q11 as the sign bit.

If the register is truncated and operated in the continuous conversion mode, a lock-up condition may occur on power-ON. This situation can be overcome by making the START input the "OR" function of $\overline{C C}$ and the appropriate register output.

The register, by suitable selection of register ladder network, can be used to perform either binary or $B C D$ conversion.

The register outputs can drive the 10 bits or less with $50 \mathrm{k} / 100 \mathrm{k}$ R/2R ladder network directly for $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ or higher. In order to drive the 12 -bit $50 \mathrm{k} / 100 \mathrm{k}$ ladder network and have the $\pm 1 / 2$ LSB resolution, the MM54C902/MM74C902 or MM54C904/MM74C904 is used as buffers, three buffers for MSB (Q11), two buffers for Q10, and one buffer for Q9.

## Typical Applications

12-Bit Successive Approximation A-to-D Converter, Operating in Continuous Mode, Drives the 50k/100k Ladder Network Directly

12-Bit Successive Approximation A-to-D Converter Operating in Continuous 8-Bit Truncated Mode


## Definition of Terms

CP: Register clock input.
$\overline{\mathrm{CC}}$ : Conversion complete-this output remains at $\mathrm{V}_{\text {OUT(1) }}$ during a conversion and goes to $\mathrm{V}_{\text {OUT(0) }}$ when conversion is complete.
D: Serial data input-connected to comparator output in A-to-D applications.
$\overline{\mathrm{E}}$ : Register enable-this input is used to expand the length of the register. When $\bar{E}$ is at $V_{1 N(1)} Q 11$ is forced to $\mathrm{V}_{\text {OUT(12 }}$ and inhibits conversion. When not used for expansion $\bar{E}$ must be connected to $\mathrm{V}_{\mathrm{IN}(0)}$ (GND).
Q11: True register MSB output.
$\overline{\mathbf{Q}} 11$ : Complement of register MSB output.
Oi ( $\mathrm{i}=0$ to 11): Register outputs.
$\overline{\mathrm{S}}$ : Start input-holding start input at $\mathrm{V}_{\text {IN }(0)}$ for at least one clock period will initiate a conversion by setting MSB (Q11) at $\mathrm{V}_{\text {OUT(0) }}$ and all other output ( $\mathrm{Q} 10-\mathrm{Q} 0$ ) at $V_{\text {OUT(1) }}$. If set-up time requirements are met, a conversion may be initiated by holding start input at $\mathrm{V}_{\text {IN }}(0)$ for less than one clock period.
DO: Serial data output-D input delayed by one clock period.

## MM54C906/MM74C906 Hex Open Drain N-Channel Buffers MM54C907/MM74C907 Hex Open Drain P-Channel Buffers

## General Description

These buffers employ monolithic CMOS technology in achieving open drain outputs. The MM54C906/ MM74C906 consists of six inverters driving six N -channel devices; and the MM54C907/MM74C907 consists of six inverters driving six P -channel devices. The open drain feature of these buffers makes level shifting or wire AND and wire OR functions by just the addition of pull-up or pull-down resistors. All inputs are protected from static discharge by diode clamps to $\mathrm{V}_{\mathrm{Cc}}$ and to ground.

## Features

- Wide supply voltage range
3.0 V to 15 V
- Guaranteed noise margin
- High noise immunity $0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.)
- High current sourcing and sinking open drain outputs


## Connection Diagram



Logic Diagrams


MM54C906/MM74C906


MM54C907/MM74C907

## Absolute Maximum Ratings (Note 1)

| Voltage at Any Input Pin | -0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$ |
| :--- | ---: |
| Voltage at any Output Pin |  |
| MM54C906/MM74C906 | -0.3 V to +18 V |
| MM54C907/MM74C907 | $\mathrm{V}_{\mathrm{CC}}-18$ to $\mathrm{V} \mathrm{CC}+0.3 \mathrm{~V}$ |
| Operating Temperature Range |  |
| MM54C906/MM54C907 | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM74C906/MM74C907 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Package Dissipation | 500 mW |
| Operating VCC Range | 3.0 V to 15 V |
| Absolute Maximum $\mathrm{V}_{\mathrm{CC}}$ | 18 V |
| Lead Temperature (Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ |

DC Electrical Characteristics Min/max limits apply across temperature range unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IN}(1)}$ | Logical "1" Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{v} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{cc}}=10 \mathrm{~V} \end{aligned}$ |  |  | 1.5 2.0 | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $\operatorname{IIN(1)}^{\text {(1) }}$ <br> $\mathrm{I}_{1 \times(0)}$ <br> $I_{c c}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
|  | Logical "0" Input Current | $\mathrm{V}_{C C}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
|  | Supply Current | $V_{C C}=15 \mathrm{~V}$, Output Open |  | 0.05 | 15 | $\mu \mathrm{A}$ |
|  | Output Leakage MM54C906 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=\mathrm{V}_{\mathrm{CC}}-1.5 \\ & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=18 \mathrm{~V} \end{aligned}$ |  | 0.005 | 5 | $\mu \mathrm{A}$ |
|  | MM74C906 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{~V}_{I N}=\mathrm{V}_{\mathrm{CC}-1.5} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=18 \mathrm{~V} \end{aligned}$ |  | 0.005 | 5 | $\mu \mathrm{A}$ |
|  | MM54C907 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=1.0 \mathrm{~V}+0.1 \mathrm{~V} \mathrm{VC} \\ & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}}-18 \mathrm{~V} \end{aligned}$ |  | 0.005 | 5 | $\mu \mathrm{A}$ |
|  | MM74C907 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=1.0 \mathrm{~V}+0.1 \mathrm{~V} \mathrm{VC} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=\mathrm{V}_{\mathrm{CC}}-18 \mathrm{~V} \end{aligned}$ |  | 0.005 | 5 | $\mu \mathrm{A}$ |
|  | CMOS/LPTTL Interface |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}-1.5 \\ & \mathrm{~V}_{\mathrm{CC}}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \hline v \\ & v \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{C C}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \\ & \hline \end{aligned}$ | $\begin{aligned} & \mathrm{v} \\ & \mathrm{v} \end{aligned}$ |
|  | Output Drive Current |  |  |  |  |  |
|  | MM54C906 | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V}, V_{\text {IN }}=1.0 \mathrm{~V}+0.1 \mathrm{~V}_{\mathrm{CC}} \\ & \mathrm{~V}_{C C}=4.5 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 2.1 \\ & 4.2 \end{aligned}$ | $\begin{aligned} & 8.0 \\ & 12 \end{aligned}$ |  | $\begin{gathered} \mathrm{mA} \\ \mathrm{~mA} \end{gathered}$ |
|  | MM74C906 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{~V}_{\text {IV }}=1.0 \mathrm{~V}+0.1 \mathrm{~V} \text { CC } \\ & \mathrm{V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.0 \mathrm{~V} \end{aligned}$ | 2.1 4.2 | 8.0 12 |  | $\underset{\mathrm{mA}}{\mathrm{~mA}}$ |
|  | MM74C907 | $\begin{aligned} & V_{c C}=4.5 \mathrm{~V}, V_{I N}=V_{C C}-1.5 \mathrm{~V} \\ & V_{C C}=4.5 \mathrm{~V}, V_{O U T}=V_{C C}-0.5 \mathrm{~V} \\ & V_{C C}=4.5 \mathrm{~V}, V_{\text {OUT }}=V_{C C}-1.0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & -1.05 \\ & -2.1 \end{aligned}$ | $\begin{aligned} & -1.5 \\ & -3.0 \end{aligned}$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
|  | MM74C907 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{~V}_{I N}=\mathrm{V}_{\mathrm{CC}}-1.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}}-0.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}}-1.0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & -1.05 \\ & -2.1 \end{aligned}$ | -1.5 -3.0 |  | $\underset{\mathrm{mA}}{\mathrm{~mA}}$ |
|  | MM54C906/MM74C906 | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N}=2.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V}, V_{\text {OUT }}=0.5 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V}, V_{\text {OUT }}=1.0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4.2 \\ & 8.4 \end{aligned}$ | $\begin{aligned} & -20 \\ & -30 \end{aligned}$ |  | $\begin{gathered} \mathrm{mA} \\ \mathrm{~mA} \end{gathered}$ |
|  | MM54C907/MM74C907 | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, V_{I N}=8.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V}, V_{O U T}=9.5 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V}, V_{\text {OUT }}=9.0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & -2.1 \\ & -4.2 \end{aligned}$ | -4.0 -8.0 |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}$, unless otherwise specified.

| Parameter |  | Conditions$\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, R=10 \mathrm{k} \\ & V_{C C}=10 \mathrm{~V}, R=10 \mathrm{k} \\ & V_{C C}=5.0 \mathrm{~V},(\text { Note } 4) \\ & V_{C C}=10 \mathrm{~V},(\text { Note } 4) \end{aligned}$ | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Delay Time to a Logical "0" |  |  |  |  |  |
|  | MM54C906/MM74C906 |  |  |  | 150 | ns |
|  |  |  |  |  | 75 | ns |
|  | MM54C907/MM74C907 |  |  |  | $150+0.7 \mathrm{RC}$ | ns |
|  |  |  |  |  | $75+0.7 \mathrm{RC}$ | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Delay Time to a Logical "1" |  |  |  |  |  |
|  | MM54C906/MM74C906 | $\mathrm{V}_{C C}=5.0 \mathrm{~V}$, (Note 4) |  |  | $150+0.7 \mathrm{RC}$ | ns |
|  |  | $\mathrm{V}_{\text {CC }}=10 \mathrm{~V}$, (Note 4) |  |  | $75+0.7 \mathrm{RC}$ | ns |
|  | MM54C907/MM74C907 | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{R}=10 \mathrm{k}$ |  |  | 150 | ns |
|  |  | $V_{C C}=10 \mathrm{~V}, \mathrm{R}=10 \mathrm{k}$ |  |  | 75 | ns |
| $\mathrm{C}_{\text {IN }}$ | Input Capacity | (Note 2) |  | 5.0 |  | pF |
| $\mathrm{C}_{\text {OUT }}$ | Output Capacity | (Note 2) |  | 20 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacity | (Note 3) Per Buffer |  | 30 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note, AN-90. (Assumes outputs are open.)
Note 4: " $C$ " used in calculating propagation includes output load capacity ( $C_{L}$ ) plus device output capactiy ( $C_{\text {OUt }}$ ).

## Typical Applications



## MM74C908/MM74C918 Dual CMOS 30-Volt Relay Driver

## General Description

The MM74C908 and MM74C918 are general purpose dual high voltage drivers, each capable of sourcing a minimum of 250 mA at $\mathrm{V}_{\text {OUT }}=\mathrm{V}_{\mathrm{CC}}-3 \mathrm{~V}$, and $\mathrm{T}_{J}=+65^{\circ} \mathrm{C}$.

The MM74C908 and MM74C918 consist of two CMOS NAND gates driving an emitter follower darlington output to achieve high current drive and high voltage capabilities. In the "OFF" state the outputs can withstand a maximum of -30 V across the device. These CMOS drivers are useful in interfacing normal CMOS voltage levels to driving relays, regulators, lamps, etc.

## Features

- Wide supply voltage range

3 V to 18 V
$0.45 V_{C C}$ (typ.)

- Low output "ON" resistance $8 \Omega$ (typ.)

■ High voltage -30V
■ High current
250 mA

## Connection Diagrams

MM74C908


MM74C918


TOP VIEW

# Absolute Maximum Ratings (Note 1) 

Voltage at Any Input Pin
Voltage at Any Output Pin
Operating Temperature Range
MM74C908/MM74C918
-0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
Operating $V_{C C}$ Range 3 V to 18 V 19V
500 mA
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
Storage Temperature Range
Lead Temperature (Soldering, 10 seconds) $300^{\circ} \mathrm{C}$
Package Dissipation Refer to Maximum Power Dissipation vs Ambient Temperature Graph

DC Electrical Characteristics Min/max limits apply across temperature range unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{c c}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical " 0 " Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | 1.5 2.0 | V |
| $\mathrm{I}_{\mathrm{IN}(1)}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I} \mathrm{N}(0)$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| $I_{\text {cc }}$ | Supply Current <br> Output "OFF" Voltage | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$, Outputs Open Circuit <br> $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\mathrm{CC}}$, l $_{\text {OUT }}=-200 \mu \mathrm{~A}$ |  | $\begin{aligned} & 0.05 \\ & -30 \end{aligned}$ | 15 | $\stackrel{\mu \mathrm{A}}{\mathrm{~V}}$ |
| CMOSILPTTL Interface |  |  |  |  |  |  |
|  | Logical "1" Input Voltage MM74C908/MM74C918 | $\mathrm{V}_{C C}=4.75 \mathrm{~V}$ | $V_{C C}-1.5$ |  |  | V |
| $V_{\text {IN(0) }}$ | Logical "0" Input Voltage MM74C908/MM74C918 | $\mathrm{V}_{\mathrm{CC}}=4.75 \mathrm{~V}$ |  |  | 0.8 | V |
| Output Drive |  |  |  |  |  |  |
| $V_{\text {OUT }}$ | Output Voltage | $\begin{aligned} & \text { I IUT }=-300 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CC}} \geqslant 5.0 \mathrm{~V}, \mathrm{~T}_{J}=25^{\circ} \mathrm{C} \\ & \text { I OUT }=-250 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CC}} \geqslant 5.0 \mathrm{~V}, \mathrm{~T}_{J}=65^{\circ} \mathrm{C} \\ & \text { I OUT }=-175 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CC}} \geqslant 5.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=150^{\circ} \mathrm{C} \end{aligned}$ | $\begin{gathered} V_{C C}-2.7 \\ V_{C C}-3.0 \\ V_{C C}-3.15 \end{gathered}$ | $\begin{aligned} & V_{C C}-1.8 \\ & V_{C C}-1.9 \\ & V_{C C}-2.0 \end{aligned}$ |  | $\begin{aligned} & \hline v \\ & v \\ & v \end{aligned}$ |
| $\mathrm{R}_{\text {ON }}$ | Output Resistance | $\mathrm{I}_{\text {OUT }}=-300 \mathrm{~mA}, \mathrm{~V}_{\text {CC }} \geqslant 5.0 \mathrm{~V}, \mathrm{~T}_{J}=25^{\circ} \mathrm{C}$ |  | 6.0 | 9.0 | $\Omega$ |
|  |  | $\mathrm{I}_{\text {OUT }}=-250 \mathrm{~mA}, \mathrm{~V}_{\text {CC }} \geqslant 2.0 \mathrm{~V}, \mathrm{~T}_{J}=65^{\circ} \mathrm{C}$ |  | 7.5 | 12 | $\Omega$ |
| $\theta_{\text {JA }}$ |  | $\mathrm{I}_{\text {OUT }}=-175 \mathrm{~mA}, \mathrm{~V}_{\text {CC }} \geqslant 5.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=150^{\circ} \mathrm{C}$ |  | 10 | 18 | $\Omega$ |
|  | Output Resistance Coefficient |  |  | 0.55 | 0.80 | \% $/{ }^{\circ} \mathrm{C}$ |
|  | Thermal Resistance MM74C908 | (Note 3) |  | 100 | 110 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
|  | MM74C918 | (Note 3) |  | 45 | 55 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## AC Electrical Characteristics

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay to a | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 150 | 300 | ns |
|  | Logic "1" | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 65 | 120 | ns |
| $t_{\text {pd0 }}$ | Propagation Delay to a | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 2.0 | 10 | $\mu \mathrm{S}$ |
|  | Logic "0" | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 4.0 | 20 | $\mu \mathrm{S}$ |
| $\mathrm{Cl}_{\text {IN }}$ | Input Capacitance | (Note 2) |  | 5.0 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\theta_{J A}$ measured in free air with device soldered into printed circuit board.

Maximum Power Dissipation vs Ambient Temperature

$T_{A}$ - AMBIENT TEMPERATURE ( ${ }^{\circ} \mathrm{C}$ )


Typical IOUT vs Typical VOUT


## AC Test Circuit



Typical IOUT vs Typical VOUT


## Switching Time Waveforms



## Power Considerations

## Calculating Output "ON" Resistance ( $R_{L}>18 \Omega$ )

The output "ON" resistance, $\mathrm{R}_{\mathrm{ON}}$, is a function of the junction temperature, $\mathrm{T}_{\mathrm{j}}$, and is given by:

$$
\begin{equation*}
\mathrm{R}_{\mathrm{ON}}=9\left(\mathrm{~T}_{\mathrm{j}}-25\right)(0.008)+9 \tag{1}
\end{equation*}
$$

and $T_{j}$ is given by:

$$
\begin{equation*}
T_{j}=T_{A}+P_{D A V} \theta_{i A}, \tag{2}
\end{equation*}
$$

where $T_{A}=$ ambient temperature, $\theta_{j A}=$ thermal resistance, and $P_{\text {DAV }}$ is the average power dissipated within the device. PDAV consists of normal CMOS power terms (due to leakage currents, internal capacitance, switching, etc.) which are insignificant when compared to the power dissipated in the outputs. Thus, the output power term defines the allowable limits of operation and includes both outputs, A and $\mathrm{B} . \mathrm{P}_{\mathrm{D}}$ is given by:

$$
\begin{equation*}
P_{D}=I_{O A}{ }^{2} R_{O N}+I_{O B}{ }^{2} R_{O N} \text {, } \tag{3}
\end{equation*}
$$

where $\mathrm{I}_{\mathrm{O}}$ is the output current, given by:

$$
\begin{equation*}
I_{O}=\frac{V_{C C}-V_{L}}{R_{O N}+R_{L}} \tag{4}
\end{equation*}
$$

$V_{L}$ is the load voltage.
The average power dissipation, $\mathrm{P}_{\mathrm{DAV}}$, is a function of the duty cycle:

$$
\left.\begin{array}{rl}
P_{\mathrm{DAV}}= & I_{\mathrm{OA}}^{2} \mathrm{R}_{\mathrm{ON}}(\text { Duty Cycle } \tag{5}
\end{array}\right)+
$$

where the duty cycle is the \% time in the current source state. Substituting equations (1) and (5) into (2) yields:

$$
\begin{equation*}
T_{j}=T_{A}+\theta_{j A}\left[9\left(T_{j}-25\right)(0.008)+9\right] \tag{6a}
\end{equation*}
$$

$$
\left[I_{O A}^{2}\left(\text { Duty Cycle }_{A}\right)+I_{O B}^{2}(\text { Duty Cycle } B)\right]
$$

simplifying:
$T_{j}=\frac{T_{A}+7.2 \theta_{\mathrm{jA}}\left[\mathrm{IOA}_{\mathrm{OA}}{ }^{2}\left(\text { Duty Cycle }{ }_{\mathrm{A}}\right)+\mathrm{I}_{\mathrm{OB}}{ }^{2}\left(\text { Duty Cycle }_{\mathrm{B}}\right)\right]}{1-0.072 \theta_{\mathrm{jA}}\left[\mathrm{I}_{\mathrm{OA}}{ }^{2}\left(\text { Duty Cycle }_{\mathrm{A}}\right)+\mathrm{I}_{\mathrm{OB}}{ }^{2}\left(\text { Duty Cycle }_{\mathrm{B}}\right)\right]}$
Equations (1), (4), and (6b) can be used in an iterative method to determine the output current, output resistance and junction temperature.


For example, let $V_{C C}=15 \mathrm{~V}, R_{L A}=100 \Omega, R_{L B}=100 \Omega$, $V_{L}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \theta_{\mathrm{jA}}=110^{\circ} \mathrm{C} / \mathrm{W}$, Duty $\mathrm{Cycle}_{\mathrm{A}}=$ $50 \%$, Duty Cycle $_{B}=75 \%$.
Assuming $R_{O N}=11 \Omega$, then:
$I_{O A}=\frac{V_{C C}-V_{L}}{R_{O N}+R_{L A}}=\frac{15}{11+100}=135.1 \mathrm{~mA}$,
$I_{O B}=\frac{V_{C C}-V_{L}}{R_{O N}+R_{L B}}=135.1 \mathrm{~mA}$
and
$T_{j}=\frac{T_{A}+7.2 \theta_{\mathrm{IA}}\left[I_{\mathrm{OA}}{ }^{2}\left(\text { Duty Cycle }{ }_{A}\right)+\mathrm{I}_{\mathrm{OB}}{ }^{2}\left(\text { Duty Cycle } \mathrm{B}_{\mathrm{B}}\right)\right]}{1-0.072 \theta_{\mathrm{jA}}^{-}\left[I_{\mathrm{OA}}{ }^{2}\left(\text { Duty Cycle }_{\mathrm{A}}\right)+\mathrm{I}_{\mathrm{OB}}{ }^{2}\left(\text { Duty Cycle } \mathrm{C}_{\mathrm{B}}\right)\right]}$
$T_{1}=\frac{25+(7.2)(110)\left[(0.1351)^{2}(0.5)+(0.1351)^{2}(0.75)\right]}{1-(0.072)(110)\left[(0.1351)^{2}(0.5)+(0.1351)^{2}(0.75)\right]}$
$\mathrm{T}_{\mathrm{j}}=52.6^{\circ} \mathrm{C}$
and $R_{O N}=9\left(T_{j}-25\right)(0.008)+9=$
$9(52.6-25)(0.008)+9=11 \Omega$

## Applications

(See AN-177 for applications.)

## MM54C910/MM74C910 256 Bit TRI-STATE ${ }^{\oplus}$ Random Access Read/Write Memory

## General Description

The MM54C910/MM74C910 is a 64 word by 4 bit random access memory. Inputs consist of six address lines, four data input lines, a WE, and a ME line. The six address lines are internally decoded to select one of 64 word locations. An internal address register latches the address information on the positive to negative transition of ME. The TRI-STATE outputs allow for easy memory expansion.

Address Operation: Address inputs must be stable ( $\mathrm{t}_{\mathrm{SA}}$ ) prior to the positive to negative transition of $\overline{M E}$, and ( $\mathrm{t}_{\mathrm{HA}}$ ) after the positive to negative transition of ME. The address register holds the information and stable address inputs are not needed at any other time.

Write Operation: Data is written into memory at the selected address if $\overline{W E}$ goes low while $\overline{M E}$ is low. $\overline{W E}$ must be held low for twe and data must remain stable $t_{\text {HD }}$ after WE returns high.

Read Operation: Data is nondestructively read from a memory location by an address operation with $\overline{W E}$ held high.

Outputs are in the TRI-STATE ( $\mathrm{Hi}-\mathrm{Z}$ ) condition when the device is writing or disabled.

## Features

| - Supply voltage range | 3.0 V to 5.5 V |
| :--- | ---: |
| - High noise immunity | $0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.) |
| - TTL compatible fan out | 1 TTL load |
| - Input address register |  |
| - Low power consumption | $250 \mathrm{nW} /$ package (typ.) <br> (chip enabled or disabled) |
| Fast access time | 250 ns (typ.) at 5.0 V |
| - TRI-STATE outputs |  |
| - High voltage inputs |  |

TRI-STATE is a registered trademark of National Semiconductor Corp.

## General Description

The MM74C911 display controller is an interface element with memory that drives a 4 -digit, 8 -segment LED display. The MM74C911 allows individual control of any segment in the 4 -digit display. The number of segments per digit can be expanded without any external components. For example, two MM74C911's can be cascaded to drive a 16 -segment alpha-numeric display.

The display controllers receive data information through 8 data lines $a, b \ldots$. . DP, and digit information through 2 address inputs K1 and K2. The input data is written into the register selected by the address information when Chip Enable, $\overline{C E}$, and Write Enable, $\overline{W E}$, are low and is latched when either $\overline{\mathrm{CE}}$ or $\overline{\mathrm{WE}}$ return high. Data hold time is not required.

A self-contained internal oscillator sequentially presents the stored data to high drive ( 100 mA typ) TRI-STATABLE output drivers which directly drive the LED display. The drivers are active when the control pin labeled Segment Output Enable, SOE, is low and go into TRISTATE ${ }^{\circledR}$ when $\overline{\text { SOE }}$ is high. This feature allows for duty cycle brightness control, or for disabling the output drive for power conservation.

The digit outputs directly drive the base of the digit transistor when the control pin labeled Digit Input Output, DIO, is low. When DIO is high, the digit lines turn into inputs and the internal scanning multiplexer is disabled.

When any digit line is forced high by an external device, usually another MM74C911, the data information for that digit is presented to the output. In this manner, 16 -segment alpha-numeric displays, 24 or 32 -segment displays, or an array of discrete LED's can be controlled by the simple cascading of expandable segment display controllers. All inputs except digit inputs are TTL compatible and do not clamp input voltages above $V_{C C}$.

## Features

- Direct segment drive ( 100 mA typ) TRI-STATABLE
- 4 registers addressed like RAM
- Internal oscillator and scanning circuit
- Direct base drive to digit transistor
- Segment expandability without external components
- TTL compatible inputs
- Power saver mode $-5 \mu \mathrm{~W}$ (typ.)


## Connection Diagram

Dual-In-Line Package


## Truth Tables

Input Control

| $\overline{\text { CE }}$ | DIGIT <br> ADDRESS |  | WE | OPERATION |
| :--- | :--- | :--- | :--- | :--- |
|  | K2 | K1 |  |  |
| 0 | 0 | 0 | 0 | Write digit 1 |
| 0 | 0 | 0 | 1 | Latch digit 1 |
| 0 | 0 | 1 | 0 | Write digit 2 |
| 0 | 0 | 1 | 1 | Latch digit 2 |
| 0 | 1 | 0 | 0 | Write digit 3 |
| 0 | 1 | 0 | 1 | Latch digit 3 |
| 0 | 1 | 1 | 0 | Write digit 4 |
| 0 | 1 | 1 | 1 | Latch digit 4 |
| 1 | X | X | X | Disable writing |

Output Control

| $\overline{\text { DIO }}$ | $\overline{S O E}$ | DIGIT LINES |  |  | OPERATION |  |
| :--- | :---: | :---: | :---: | :---: | :---: | :--- |
|  |  | D4 | D3 | D2 | D1 |  |
| 0 |  | $R$ | $R$ | $R$ | $R$ | Refresh display |
| 0 |  | $R$ | $R$ | $R$ | $R$ | Disable segment outputs |
| 1 | 0 | 0 | 0 | 0 | 0 | Digits are now inputs |
| 1 | 0 | 0 | 0 | 0 | 1 | Display digit 1 |
| 1 | 0 | 0 | 0 | 1 | 0 | Display digit 2 |
| 1 | 0 | 0 | 1 | 0 | 0 | Display digit 3 |
| 1 | 0 | 1 | 0 | 0 | 0 | Display digit 4 |
| 1 | 1 | 0 | 0 | 0 | 0 | Power saver mode |

$R=$ Refresh (digit lines sequentially pulsed)
X = Don't care

## Absolute Maximum Ratings (Notes 1 and 2 )

| Voltage at Any Pin Except Inputs | -0.3 V to $\mathrm{VCC}+0.3 \mathrm{~V}$ |
| :--- | ---: |
| Voltage at Any Input Except Digits | -0.3 V to +15 V |
| Operating Temperature Range, $\mathrm{T}_{\mathrm{A}}$ | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Package Dissipation | Refer to $\mathrm{PD}(\mathrm{MAX})$ vs TA Graph |
| Operating $\mathrm{V}_{\mathrm{CC}}$ Range | 3 V to 6 V |
| Absolute Maximum $V_{\text {CC }}$ | 6.5 V |
| Lead Temperature (Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ |

DC Electrical Characteristics $\mathrm{Min} / \max$ limits apply at $-40^{\circ} \mathrm{C} \leq T_{J} \leq+85^{\circ} \mathrm{C}$, unless otherwise noted

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| VIN(1) | Logical "1" Input Voltage | $V_{C C}=5 \mathrm{~V}$ | 3.0 |  |  | V |
| VIN(0) | Logical "0" Input Voltage |  |  |  | 1.5 | $\checkmark$ |
| IIN(1) | Logical "1" Input Current | $V_{C C}=5 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| IIN(0) | Logical " 0 " Input Current | $V_{C C}=5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| ICC | Supply Current (Normal) | $V_{C C}=5 \mathrm{~V}$. Outputs Open |  | 0.50 | 2.5 | mA |
| I'c | Supply Current (Power Saver) | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \overline{\mathrm{SOE},} \overline{\mathrm{DIO}}=" 1 ", \\ & \mathrm{D} 1, \mathrm{D} 2, \mathrm{D} 3, \mathrm{D} 4=" 0 " \end{aligned}$ |  | 1 | 600 | $\mu \mathrm{A}$ |
| IOUT | TRI-STATE Output Current | $\begin{aligned} & V_{O}=5 \mathrm{~V} \\ & V_{O}=0 V \end{aligned}$ | -10 | $\begin{array}{r} 0.03 \\ -0.03 \end{array}$ | 10 | $\mu \mathrm{A}$ |

CMOS/LPTTL INTERFACE

| $V_{\text {IN }}(1)$ | Logical "1" Input Voltage | $V_{C C}=4.75 \mathrm{~V}$ | $V_{C C}-2.0$ |  |  |
| :--- | :--- | :--- | :--- | :--- | :--- |
| $V_{\text {IN }}(0)$ | Logical " 0 " Input Voltage | $V_{C C}=4.75 \mathrm{~V}$ |  | $V$ |  |

OUTPUT DRIVE


Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Range", they are not meant to imply that the device should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: All voltage reference to ground.
Note 3: $\theta_{\text {JA }}$ measured in free-air with device soldered into printed circuit board.

AC Electrical Characteristics $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$

| PARAMETER |  | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tCW | Chip Enable to Write Enable Set－Up Time | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | 35 | 15 |  | ns |
|  |  | $\mathrm{TJ}=125^{\circ} \mathrm{C}$ | 50 | 20 |  | ns |
| ${ }^{\text {t }}$ AW | Address to Write Enable Set－Up Time | $\mathrm{TJ}=25^{\circ} \mathrm{C}$ | 35 | 15 |  | ns |
|  |  | $\mathrm{TJ}=125^{\circ} \mathrm{C}$ | 50 | 20 |  | ns |
| tWW | Write Enable Width | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | 400 | 225 |  | ns |
|  |  | $\mathrm{TJ}=125^{\circ} \mathrm{C}$ | 450 | 250 |  | ns |
| tDW | Data to Write Enable Set－Up Time | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | 390 | 225 |  | ns |
|  |  | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ | 430 | 250 |  | ns |
| tWD | Write Enable to Data Hold Time | $\mathrm{T}_{J}=25^{\circ} \mathrm{C}$ | 0 | －10 |  | ns |
|  |  | $\mathrm{T}_{J}=125^{\circ} \mathrm{C}$ | 0 | －15 |  | ns |
| tWA | Write Enable to Address Hold Time | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | 0 | －10 |  | ns |
|  |  | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ | 0 | $-15$ |  | ns |
| twC W | Write Enable to Chip Enable Hold Time | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | 55 | 30 |  | ns |
|  |  | $T_{J}=125^{\circ} \mathrm{C}$ | $75$ | 40 |  | ns |
| t1H，toh Logical＂1＂，Logical＂0＂Levels into TRI－STATE |  | $\begin{aligned} & R_{L}=10 k, C_{L}=10 p F \\ & T_{J}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 275 | 500 | ns |
|  |  | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ |  | 325 | 600 | ns |
| ${ }^{\text {t }} \mathrm{H} 1, \mathrm{t} \mathrm{HO}$ | TRI－STATE to Logical＂ 1 ＂or Logical＂0＂ | $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  |  |  |  |
|  | Levels | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | 325 | 600 | ns |
|  |  | $\mathrm{T}_{J}=125^{\circ} \mathrm{C}$ |  | 375 | 700 | ns |
| ${ }^{\text {t }}$ 1，${ }^{\text {t }} 0$ | Propagation Delay From Digit Input to | $T J=25^{\circ} \mathrm{C}$ |  | 500 | 1000 | ns |
|  | Segment Output | $\mathrm{TJ}=125^{\circ} \mathrm{C}$ |  | 700 | 1400 | ns |
| ${ }_{\text {I }}$ B | Interdigit Blanking Time | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | 5 | 10 |  | $\mu \mathrm{s}$ |
|  |  | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ | 10 | 20 |  | $\mu \mathrm{s}$ |
| ${ }^{\text {f M }}$ MX | Multiplex Scan Frequency | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | 525 |  | $\mathrm{Hz}$ |
|  |  | $T_{J}=125^{\circ} \mathrm{C}$ |  | 375 |  | Hz |
| CIN | Input Capacitance | （Note 4） |  | 5 | 7.5 | pF |
| COUT | TRI－STATE Output Capacitance | （Note 4） |  | 30 | 50 | pF |

Note 4：Capacitance guaranteed by periodic testing．

## Switching Time Waveforms



## TRI－STATE Waveforms




Read Data Waveforms


Note 1: All other digit lines are at a low level. $\overline{\mathrm{DIO}}$ at a high level.

## Functional Description

The MM74C911 display controller is manufactured on standard metal gate CMOS technology. A single 5 V 74 series TTL supply can be used for power and should be bypassed at the VCC pin to suppress current transients.

The digit outputs directly drive the base of a grounded emitter digit transistor without the need of a Darlington configuration. If an MM74C911 is driving a digit transistor and also supplying digit information to a cascaded MM74C911, base resistors are needed in the digit transistors to provide an adequate high level to the digit inputs of the cascaded MM74C911.

As seen in the block diagram, these display controllers contain four 8 -bit registers; any one may be randomly
written into. In normal operation, the internal multiplexer scans the registers and refreshes the display. In cascaded operation, 1 MM74C911 serves as a master refresh device and cascaded MM74C911's are slaved to it through digit lines operating as inputs.

The MM74C911 appears to a microprocessor as memory and to the user as a self-scan display. Since every segment is under microprocessor control, great versatility is obtained.

Low power standby operation occurs with both $\overline{\text { SOE }}$ and $\overline{\mathrm{DIO}}$ inputs high. This condition forces the MM74C911 to a quiescent state typically drawing less than $1 \mu \mathrm{~A}$ of supply current with a standby supply voltage as low as 3 V .

## Block Diagram



## Typical Performance Characteristics



Note 1: Segment outputs if shorted to ground will exceed maximum power dissipation of the device.
Note 2: $\mathrm{V}_{C E}$ is the saturation voltage of the digit drive transistor.

## Applications

Segment Output Structure




National Semiconductor
MM74C912 6-Digit BCD Display Controller/Driver MM74C917 6-Digit Hex Display Controller/Driver

## General Description

The MM74C912, MM74C917 display controllers are interface elements, with memory, that drive a 6 -digit, 8 -segment LED display.

The display controllers receive data information through 5 data inputs $A, B, C, D$ and DP, and digit information through 3 address inputs K 1 , K 2 and K 3 .

The input data is written into the register selected by the address information when $\overline{\mathrm{CHIP}} \mathrm{ENABLE}, \overline{\mathrm{CE}}$, and $\overline{\text { WRITE ENABLE, }} \overline{W E}$, are low and is latched when either $\overline{\mathrm{CE}}$ or $\overline{\mathrm{WE}}$ return high. Data hold time is not required. A self-contained internal oscillator sequentially presents the stored data to a decoder where 4 data bits control the format of the displayed character and 1 bit controls the decimal point. The internal oscillator is controlled by a control input labeled OSCILLATOR ENABLE, $\overline{\text { OSE, }}$ which is tied low in normal operation. A high level at $\overline{\text { OSE }}$ prevents automatic refresh of the display.

The 7 -segment plus decimal point output information directly drives a LED display through high drive (100
mA typ) output drivers. The drivers are active when the control pin labeled SEGMENT OUTPUT ENABLE, SOE, is low and go into TRI-STATE ${ }^{\circledR}$ when $\overline{S O E}$ is high. This feature allows for duty cycle brightness control and for disabling the output drivers for power conservation.

The MM74C912 segment decoder converts BCD data into 7 -segment format. The MM74C917 converts binary data into hex format.

All inputs are TTL compatible and do not clamp to the $V_{\text {CC }}$ supply.

## Features

- Direct segment drive ( 100 mA typ) TRI-STATEABLE
- 6 registers addressed like RAM
- Internal oscillator and scanning circuit
- Direct base drive to digit transistor ( 20 mA typ)
- Internal segment decoder
- TTL compatible inputs


## Connection Diagram

## Dual-In-Line Package



Truth Tables
Input Control

| $\overline{\text { CE }}$ | DIGIT ADDRESS |  |  | $\overline{W E}$ | OPERATION |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | K3 | K2 | K1 |  |  |
| 0 | 0 | 0 | 0 | 0 | Write Digit 1 |
| 0 | 0 | 0 | 0 | 1 | Latch Digit 1 |
| 0 | 0 | 0 | 1 | 0 | Write Digit 2 |
| 0 | 0 | 0 | 1 | 1 | Latch Digit 2 |
| 0 | 0 | 1 | 0 | 0 | Write Digit 3 |
| 0 | 0 | 1 | 0 | 1 | Latch Digit 3 |
| 0 | 0 | 1 | 1 | 0 | Write Digit 4 |
| 0 | 0 | 1 | 1 | 1 | Latch Digit 4 |
| 0 | 1 | 0 | 0 | 0 | Write Digit 5 |
| 0 | 1 | 0 | 0 | 1 | Latch Digit 5 |
| 0 | 1 | 0 | 1 | 0 | Write Digit 6 |
| 0 | 1 | 0 | 1 | 1 | Latch Digit 6 |
| 0 | 1 | 1 | 0 | 0 | Write Null Digit |
| 0 | 1 | 1 | 0 | 1 | Latch Null Digit |
| 0 | 1 | 1 | 1 | 0 | Write Null Digit |
| 0 | 1 | 1 | 1 | 1 | Latch Null Digit |
| 1 | X | X | X | x | Disable Writing |

X = don't care

Output Control

| $\overline{\text { SOE }}$ | $\overline{\text { OSE }}$ | OPERATION |
| :---: | :---: | :--- |
| 0 | 0 | Refresh Display |
| 0 | 1 | Stop Oscillator* |
| 1 | 0 | Disable Segment Outputs |
| 1 | 1 | Standby Mode |

*Segment drive may exceed maximum display dissipation.

Absolute Maximum Ratings (Notes 1 and 2 )

Voltage at Any Pin Except Inputs -0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
Voltage at Any Input $\quad-0.3 \mathrm{~V}$ to +15 V
Operating Temperature Range ( $\mathrm{TA}_{\mathrm{A}}$ ) $\quad-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
Storage Temperature Range $\quad-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$

Package Dissipation Refer to PD MAX vs $\mathrm{TA}_{\mathrm{A}}$ Graph Operating $V_{C C}$ Range 3 V to 6 V
Absolute Maximum VCC 6.5 V

Lead Temperature (Soldering, 10 seconds) $\quad 300^{\circ} \mathrm{C}$

DC Electrical Characteristics Min/max limits apply at $40^{\circ} \mathrm{C} \leq \mathrm{TJ} \leq 85^{\circ} \mathrm{C}$, unless otherwise noted.

| PARAMETER |  | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS TO CMOS |  |  |  |  |  |  |
| VIN(1) | Logical "1" Input Voltage | $V_{C C}=5 \mathrm{~V}$ | 3.0 |  |  | V |
| $\mathrm{VIN}(0)$ | Logical " 0 " Input Voltage | $V_{C C}=5 \mathrm{~V}$ |  |  | 1.5 | V |
| IIN(1) | Logical "1" Input Current | $V_{C C}=5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| IIN(0) | Logical " 0 " Input Current | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| ${ }^{\prime} \mathrm{Cc}$ | Supply Current | $V_{C C}=5 \mathrm{~V}$, Outputs Open |  | 0.5 | 2 | mA |
| IOUT | TRI-STATE Output Current | $V_{C C}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=5 \mathrm{~V}$ |  | 0.03 | 10 | $\mu \mathrm{A}$ |
|  |  | $V_{C C}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0 \mathrm{~V}$ | -10 | -0.03 |  | $\mu \mathrm{A}$ |

## CMOS/LPTTL INTERFACE

| VIN(1) <br> VIN(0) | Logical " 1 " Input Voltage Logical " 0 " Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.75 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\mathrm{V}_{\mathrm{CC}}{ }^{-2.0}$ |  | 0.8 | V V |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| OUTPUT DRIVE |  |  |  |  |  |  |
| ${ }^{\text {S }} \mathrm{H}$ | High Level Segment Current | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, V_{\mathrm{O}}=3.4 \mathrm{~V}, \\ & T_{J}=25^{\circ} \mathrm{C} \\ & T_{J}=100^{\circ} \mathrm{C} \end{aligned}$ | $\begin{aligned} & -60 \\ & -40 \end{aligned}$ | $\begin{aligned} & -100 \\ & -60 \end{aligned}$ |  | $m A$ $m A$ |
| ${ }^{\text {I }}$ DH | High Level Digit Current | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}, \\ & \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{J}}=100^{\circ} \mathrm{C} \end{aligned}$ | -10 -7 | $\begin{aligned} & -20 \\ & -15 \end{aligned}$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| VOUT(1) | Logical " 1 " Output Voltage Any Digit | $V_{C C}=5 \mathrm{~V}, \mathrm{I}^{\prime}=-360 \mu \mathrm{~A}$ | 4.6 |  |  | V |
| VOUT(0) | Logical " 0 " Output Voltage Any Output | $V_{C C}=5 \mathrm{~V}, 1 \mathrm{O}=360 \mu \mathrm{~A}$ |  |  | 0.4 | V |
| $\Theta_{J A}$ | Thermal Resistance | (Note 3) |  | 100 |  | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Range" they are not meant to imply that the device should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: All voltages reference to ground.
Note 3: $\Theta_{J A}$ measured in free air with device soldered into printed circuit board.

AC Electrical Characteristics $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tcW | Chip Enable to Write Enable | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | 35 | 15 |  | ns |
|  | Setup Time | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ | 50 | 20 |  | ns |
| ${ }^{\text {t }}$ AW | Address to Write Enable | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | 35 | 15 |  | ns |
|  | Setup Time | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ | 50 | 20 |  | ns |
| tww | Write Enable Width | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | 400 | 225 |  | ns |
|  |  | $\mathrm{T}_{J}=125^{\circ} \mathrm{C}$ | 450 | 250 |  | ns |

AC Electrical Characteristics (Continued) $V_{C C}=5 \mathrm{~V}, \mathrm{t}_{\mathrm{r}}=\mathrm{tf}_{\mathrm{f}}=20 \mathrm{~ns}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tDW | Data to Write Enable Setup Time | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | 390 | 225 |  | ns |
|  |  | $\mathrm{T}_{J}=125^{\circ} \mathrm{C}$ | 430 | 250 |  | ns |
| twD | Write Enable to Data Hold Time | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | 0 | -10 |  | ns |
|  |  | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ | 0 | -15 |  | ns |
| tWA | Write Enable to Address Hold Time | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | 0 | -10 |  | ns |
|  |  | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ | 0 | -15 |  | ns |
| ${ }^{\text {tw }}$ | Write Enable to Chip Enable | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | 50 | 30 |  | ns |
|  | Hold Time | $\mathrm{T}_{J}=125^{\circ} \mathrm{C}$ | 75 | 40 |  | ns |
| ${ }^{\text {t1 }} \mathrm{H}, \mathrm{t} 0 \mathrm{H}$ | Logical " 1 ", Logical " 0 " Levels | $R_{L}=10 \mathrm{k}, \mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | 275 | 500 | ns |
|  | Into TRI-STATE | $\mathrm{C}_{\mathrm{L}}=10 \mathrm{pF}, \mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ |  | 325 | 600 | ns |
| ${ }_{\text {the }}$, tHO | TRI-STATE to Logical " 1 " to | $R_{L}=10 \mathrm{k}, \mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | 325 | 600 | ns |
|  | Logical "0" Level | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ |  | 375 | 700 | ns |
| t\|B | Interdigit Blanking Time | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | 5 | 10 |  | $\mu \mathrm{s}$ |
|  |  | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ | 10 | 20 |  | $\mu \mathrm{s}$ |
| ${ }_{\text {f M }}$ | Multiplex Scan Frequency | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | 350 |  | Hz |
|  |  | $\mathrm{TJ}=125^{\circ} \mathrm{C}$ |  | 250 |  | Hz |
| $\mathrm{CIN}^{\text {IN }}$ | Input Capacitance | Note 4 |  | 5 | 7.5 | pF |
| Cout | TRI-STATE Output Capacitance | Note 4 |  | 30 | 50 | pF |

Note 4: Capacitance is guranteed by periodic testing.

## Switching Time Waveforms



| MM74C917 | $\mathrm{Hi}-\mathrm{Z}$ | /T | 1 |  |  | $11$ |  |  | $7$ |  |  |  |  | I- |  |  | F | F |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| MM74C912 | $\mathrm{Hi}-\mathrm{Z}$ | $1 /$ | 1 |  | $-1$ | $1 /$ |  |  | $7$ |  |  | 1-1 | $15$ | - | - | - |  | $\bullet$ |
| Input A $2^{0}$ | $X$ | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 1 |
| Data B $2^{1}$ | X | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 1 |
| C $2^{2}$ | $x$ | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 |
| D $2^{3}$ | X | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 |
| DP | X | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 |
| Output Enable $\overline{\text { SOE }}$ | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |

Segment Identification


The MM74C912, MM74C917 display controllers are manufactured using metal gate CMOS technology. A single 5V 74 series TTL supply can be used for power and should be bypassed at the $V_{C C}$ pin.

All inputs are TTL compatible; the segment outputs drive the LED display directly through current limiting resistors. The digit outputs are designed to directly drive the base of a grounded emitter digit transistor without the need of a Darlington configuration.

As seen in the block diagram, these display controllers contain six 5-bit registers; any one of which may be randomly written. The internal multiplexer scans the registers and refreshes the display. This combination of write only memory and self-scan display makes the display controller a "refreshing experience" for an overburdened microprocessor.

## Block Diagram



Typical Performance Characteristics

Note 1: Segment outputs if shorted to ground will exceed maximum power dissipation of the device. Note 2: $\mathrm{V}_{\text {CE }}$ is the saturation voltage of the digit drive transistor.

## Segment Output Structure

Digit Output Structure



Input Protection


## Typical Applications



## MM54C914/MM74C914 Hex Schmitt Trigger with Extended Input Voltage

## General Description

The MM54C914/MM74C914 is a monolithic CMOS Hex Schmitt trigger with special input protection scheme. This scheme allows the input voltage levels to exceed $\mathrm{V}_{\mathrm{cc}}$ or ground by at least $10 \mathrm{~V}\left(\mathrm{~V}_{\mathrm{cc}}-25 \mathrm{~V}\right.$ to GND + 25 V ), and is valuable for applications involving voltage level shifting or mismatched power supplies.

The positive and negative-going threshold voltages, $\mathrm{V}_{\mathrm{T}+}$ and $\mathrm{V}_{\mathrm{T}-}$, show low variation with respect to temperature (typ $0.0005 \mathrm{~V} /{ }^{\circ} \mathrm{C}$ at $\mathrm{V}_{\mathrm{cc}}=10 \mathrm{~V}$ ). And the hysteresis, $\mathrm{V}_{\mathrm{T}+}-\mathrm{V}_{\mathrm{T}-} \geq 0.2 \mathrm{~V}_{\mathrm{Cc}}$ is guaranteed.

## Features

- Hysteresis
- Special input protection
- Wide supply voltage range
- High noise immunity
- Low power TTL compatibility
$0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.)
$0.2 \mathrm{~V}_{\text {cc }}$ guaranteed
Extended Input Voltage Range
3.0 V to 15 V
$0.70 \mathrm{~V}_{\mathrm{Cc}}$ (typ.)
fan out of 2 driving 74L


## Connection Diagram




## Absolute Maximum Ratings

Voltage at Any Input Pin
Voltage at Any Other Pin
Operating Temperature Range


MM74C914
Storage Temperature Range
Package Dissipation
Operating $V_{C C}$ Range
Absolute Maximum $\mathrm{V}_{\mathrm{CC}}$
Lead Temperature (Soldering, 10 seconds)

$$
V_{C C}-25 V \text { to } G N D+25 V
$$

$$
-0.3 \mathrm{~V} \text { to } \mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}
$$

$$
-55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C}
$$

$$
-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C}
$$

$$
-65^{\circ} \mathrm{C} \text { to }+150^{\circ} \mathrm{C}
$$

$$
500 \mathrm{~mW}
$$

3.0 V to 15 V

18 V
$300^{\circ} \mathrm{C}$

DC Electrical Characteristics min./max. limits apply across temperature range unless otherwise noted.


AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

| Parameter | Conditions | Min. | Typ. | Max. | Units |  |
| :---: | :--- | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{C}_{\mathrm{pd}}$ | Propagation Delay from Input to Output | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  | 220 | 400 | ns |
|  |  | $\mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}$ |  | 80 | 200 | ns |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance | Any Input (Note 2) |  | 5.0 |  | pF |
| $\mathrm{C}_{\mathrm{PD}}$ | Power Dissipation Capacitance | (Note 3) Per Gate |  | 20 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $C_{P D}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note, AN-90.
Note 4: Only one input is at $1 / 2 V_{C C}$, the others are either at $V_{C C}$ or GND.

## Typical Application



## Typical Performance Characteristics



## MM54C915/MM74C915 7-Segment-to-BCD Converter

## General Description

The MM54C915/MM74C915 is a monolithic complementary MOS (CMOS) integrated circuit, constructed with N and P -channel enhancement-mode transistors. This circuit accepts 7 -segment information and converts it into BCD information. The true state of the Segment inputs can be selected by use of the Invert/Non-invert control pin. A logical " 0 " on the Invert/Non-invert control pin selects active high true decoding at the Segment inputs. A logical " 1 " on the Invert/Non-invert control pin selects active low true decoding at the Segment inputs. In addition to 4 TTL compatible BCD outputs, an Error output and Minus output are available. The Error output goes to an active " 1 " whenever a non-standard 7 -segment code appears at the Segment inputs. The BCD outputs are forced into a TRI-STATE ${ }^{\circledR}$ condition when an error is detected. This allows the user to program his own error code by tying the BCD outputs to VCC or Ground via high value resistors (~500k). The BCD outputs may also be forced into TRI-STATE by a logical " 1 " on output enable ( $\overline{\mathrm{OE}}$ ).

The Minus output goes to a logical " 1 " whenever a minus code is detected and is useful as a microprocessor interrupt. The BCD outputs are in a flow-though condition when Latch Enable (LE) is at a logical " 0 ", and latched when LE is at a logical " 1 ". The inputs will not clamp signals to the positive supply, allowing simple level translation from MOS to TTL.

## Features

- Wide supply range
$3 \mathrm{~V}-15 \mathrm{~V}$
- High noise immunity
$0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.)
- TTL compatible fan out

1 TTL load

- Selectable active true inputs
- TRI-STATE outputs
- On-chip latch
- Error output
- Minus output


## Logic and Connection Diagrams



Absolute Maximum Ratings

Voltage at Any Output
Voltage at Any Input
Operating Temperature Range MM54C915
MM74C915
-0.3 V to $\mathrm{VCC}+0.3 \mathrm{~V}$
-0.3 V to 18 V
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

Storage Temperature Range
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ Package Dissipation Operating VCC Range Maximum VCC Lead Temperature, (Soldering, 10 seconds)

DC Electrical Characteristics Min/max limits apply across temperature range, unless otherwise noted.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS TO CMOS |  |  |  |  |  |  |
| VIN(1) | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.3 \\ & 8 \\ & 12.5 \end{aligned}$ | $\begin{aligned} & \hline 4.5 \\ & 9 \\ & 13.5 \end{aligned}$ |  | V v v |
| VIN(0) | Logical " 0 " Input Voltage | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.5 \\ & 1 \\ & 1.5 \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 2 \\ & 2.5 \end{aligned}$ | $v$ $v$ $v$ |
| IIN(1) | Logical " 1 " Input Current | $V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1 | $\mu \mathrm{A}$ |
| IIN(0) | Logical "0" Input Current | $V_{\text {IN }}=0 \mathrm{~V}$ | -1 | -0.005 |  | $\mu \mathrm{A}$ |
| VOUT(1) | Logical "1" Output Voltage | $\begin{aligned} & \mathrm{I}_{\mathrm{O}}=10 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 4.5 \\ & 9 \\ & 13.5 \end{aligned}$ |  | V v v |
| VOUT(0) | Logical "0" Output Voltage | $\begin{aligned} & I_{O}=10 \mu \mathrm{~A} \\ & V_{C C}=5 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.5 \\ & 1 \\ & 1.5 \end{aligned}$ |  | V V V |
| I'C | Supply Current | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.25 \\ & 0.75 \\ & 1.00 \end{aligned}$ | $\begin{aligned} & 1 \\ & 2.5 \\ & 3 \end{aligned}$ | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \\ & \mathrm{~mA} \end{aligned}$ |

CMOS/TTL INTERFACE

| VIN(1) | Logical "1" Input Voltage MM54C915 MM74C915 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & v_{\mathrm{CC}^{-1}}{ }^{-1.7} \\ & \mathrm{v}_{\mathrm{CC}}{ }^{-1.7} \end{aligned}$ |  |  | V V |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| V IN(0) | ```Logical "0" Input Voltage MM54C915 MM74C915``` | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \\ & V_{C C}=4.75 \mathrm{~V} \end{aligned}$ |  |  | 0.8 0.8 | V v |
| , VOUT(1) | Logical "1" Output Voltage MM54C915 MM74C915 | $\begin{aligned} & \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | V v |
| VOUT(0) | Logical " 0 " Output Voltage MM54C915 MM74C915 | $\begin{aligned} & \mathrm{I}_{\mathrm{O}}=1.6 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & \mathrm{~V}_{C C}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | V |
| OUTPUT DRIVE (Short Circuit Current) |  |  |  |  |  |  |
| ISOURCE | Output Source Current <br> P-Channel | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{O}}=0 \mathrm{~V}$ <br> (Note 2) $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & -1.75 \\ & -8 \\ & -15 \end{aligned}$ | $\begin{aligned} & -3.3 \\ & -15 \\ & -25 \end{aligned}$ |  | mA <br> $m A$ <br> mA |
| ISINK | Output Sink Current <br> N -Channel | $T_{A}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{O}}=\mathrm{V}_{\mathrm{CC}}$ <br> (Note 2) $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 5 \\ & 20 \\ & 30 \end{aligned}$ | $\begin{aligned} & 8 \\ & 30 \\ & 50 \end{aligned}$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \\ & \mathrm{~mA} \end{aligned}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}$

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd}} 0, \mathrm{t}_{\text {pd }} 1$ | Propagation Delay Time to | $C_{L}=50 \mathrm{pF}$ |  |  |  |  |
|  | Logical " 0 ' or a Logical ' 3 " | $V_{C C}=5 \mathrm{~V}$ |  | 500 | 1000 | ns |
|  |  | $V_{C C}=10 \mathrm{~V}$ |  | 300 | 600 | ns |
|  |  | $V_{C C}=15 \mathrm{~V}$ |  | 300 | 600 | ns |
| $\mathrm{t}_{0} \mathrm{H}, \mathrm{t}_{1} \mathrm{H}$ | Propagation Delay Time From | $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=10 \mathrm{pF}$ |  |  |  |  |
|  | Logical " 0 " or Logical " 1 " | $V_{C C}=5 \mathrm{~V}$ |  | 110 | 200 | ns |
|  | into High Impedance State | $V_{C C}=10 \mathrm{~V}$ |  | 75 | 130 | ns |
|  |  | $V_{C C}=15 \mathrm{~V}$ |  | 60 | 110 | ns |
| tho, thi | Propagation Delay Time From | $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  |  |  |  |
|  | High Impedance State to a | $\mathrm{V}_{C C}=5 \mathrm{~V}$ |  | 150 | 250 | ns |
|  | Logical " 0 " or Logical " 1 " | $V_{C C}=10 \mathrm{~V}$ |  | 80 | 140 | ns |
|  |  | $V_{C C}=15 \mathrm{~V}$ |  | 70 | 125 | ns |
| $\mathrm{t}_{\text {s }}$ | Input Data Set-Up Time | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  |  |  |  |
|  |  | $V_{C C}=5 \mathrm{~V}$ |  | 500 | 1000 | ns |
|  |  | $V_{C C}=10 \mathrm{~V}$ |  | 300 | 600 | ns |
|  |  | $V_{C C}=15 \mathrm{~V}$ |  | 300 | 600 | ns |
| th | Input Data Hold Time | $C_{L}=50 \mathrm{pF}$ |  |  |  |  |
|  |  | $V_{C C}=5 V$ |  | -150 | 0 | ns |
|  |  | $V_{C C}=10 \mathrm{~V}$ |  | -100 | 0 | ns |
|  |  | $V_{C C}=15 \mathrm{~V}$ |  | -100 | 0 | ns |
| CIN | Input Capacitance | Any Input, (Note 3) |  | 5 | 7.5 | pF |
| COUT | TRI-STATE Output Capacitance | Any Output, (Note 3) |  | 10 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: These specifications apply to transient operation. It is not meant to imply that the device should be operated at these limits in sustained operation.
Note 3: Capacitance is guaranteed by periodic testing.

## Truth Table

| CHARACTER AT SEGMENT INPUTS | BCD OUTPUTS |  |  |  | NON-BCD OUTPUTS |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | $\begin{gathered} D \\ 2^{3} \end{gathered}$ | $\begin{aligned} & \hline \mathrm{C} \\ & \mathbf{2}^{2} \end{aligned}$ | $\begin{aligned} & \hline B \\ & 2^{1} \end{aligned}$ | $\begin{aligned} & \text { A } \\ & 2^{0} \end{aligned}$ |  |  |
|  |  |  |  |  | ERROR | MINUS |
| [7] | 0 | 0 | 0 | 0 | 0 | 0 |
| d. | 0 | 0 | 0 | 1 | 0 | 0 |
| b | 0 | 0 | 0 | 1 | 0 | 0 |
| ${ }^{\text {c }}$ | 0 | 0 | 1 | 0 | 0 | 0 |
| J | 0 | 0 | 1 | 1 | 0 | 0 |
| 4 | 0 | 1 | 0 | 0 | 0 | 0 |
| 5 | 0 | 1 | 0 | 1 | 0 | 0 |
| E | 0 | 1 | 1 | 0 | 0 | 0 |
| $b$ | 0 | 1 | 1 | 0 | 0 | 0 |
| 7 | 0 | 1 | 1 | 1 | 0 | 0 |
| 日 | 1 | 0 | 0 | 0 | 0 | 0 |
| 4 | 1 | 0 | 0 | 1 | 0 | 0 |
| 4 | 1 | 0 | 0 | 1 | 0 | 0 |
|  | 1 | 1 | 1 | 1 | 0 | 0 |
| $\cdots$ | x | X | X | x | 1 | 1 |
| All other input | X | X | X | X | 1 | 0 |
| combinations | X | X | X | X | 1 | 0 |

SEGMENT IDENTIFICATION


[^5]
## Typical Applications



## General Description

The MM54C920/MM74C920 $256 \times 4$ random access read/ write memory is manufactured using silicon gate CMOS technology. Data output is the same polarity as data input. Internal latches store address inputs, CES and data output. This RAM is specifically designed to operate from standard 54/74 TTL power supplies. All inputs and outputs are TTL compatible.

The MM54C921/MM74C921 is identical to the MM54C920/ MM74C920, except data inputs are internally connected to data outputs; the number of package leads is thereby reduced to 18.

Complete address decoding as well as 2-chip select functions, CEL and CES, and TRI-STATE ${ }^{\oplus}$ outputs allow easy expansion with a minimum of external components. Ver-
satility plus high speed and low power make these RAMs ideal elements for use in microprocessor, minicomputer, as well as main frame memory applications.

## Features

- $256 \times 4$-bit organization
- Access time

250 ns max. MM74C920, MM74C921
275 ns max. MM54C920, MM54C921
300 ns max. MM74C920-3, MM74C921-3

- TRI-STATE outputs
- Low power
- On-chip registers
- Single 5 V supply
- Data retained with $V_{C C}$ as low as 2 V

See page 4-15
for detailed specifications

## MM54C922/MM74C922 16-Key Encoder <br> MM54C923/MM74C923 20-Key Encoder

## General Description

These CMOS key encoders provide all the necessary logic to fully encode an array of SPST switches. The keyboard scan can be implemented by either an external clock or external capacitor. These encoders also have onchip pull-up devices which permit switches with up to $50 \mathrm{k} \Omega$ on resistance to be used. No diodes in the switch array are needed to eliminate ghost switches. The internal debounce circuit needs only a single external capacitor and can be defeated by omitting the capacitor. A Data Available output goes to a high level when a valid keyboard entry has been made. The Data Available output returns to a low level when the entered key is released, even if another key is depressed. The Data Available will return high to indicate acceptance of the new key after a normal debounce period; this two key roll over is provided between any two switches.

An internal register remembers the last key pressed even after the key is released. The TRI-STATE ${ }^{\circledR}$ outputs
provide for easy expansion and bus operation and are LPTTL compatible.

## Features

- $50 \mathrm{k} \Omega$ maximum switch on resistance
- On or off chip clock
- On chip row pull-up devices
- 2 key roll-over
- Keybounce elimination with single capacitor
- Last key register at outputs
- TRI-STATE outputs LPTTL compatible
- Wide supply range

3 V to 15 V

- Low power consumption


## Connection Diagrams



Voltage at Any Pin Operating Temperature Range MM54C922, MM54C923
MM74C922, MM74C923
Storage Temperature Range
$V_{C C}-0.3 V$ to $V_{C C}+0.3 V$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$

Package Dissipation
500 mW
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
$V_{C C}$
Lead Temperature (Soldering, 10 seconds)

3 V to 15 V

18 V
$300^{\circ} \mathrm{C}$

DC Electrical Characteristics Min/Max limits apply across temperature range unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to cmos |  |  |  |  |  |  |
| $V_{\mathrm{T}+}$ | Positive-Going Threshold Voltage at Osc and KBM Inputs | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \quad I_{I N} \geq 0.7 \mathrm{~mA} \\ & V_{C C}=10 \mathrm{~V}, \quad I_{\mathrm{N}} \geq 1.4 \mathrm{~mA} \\ & V_{C C}=15 \mathrm{~V}, \quad \mathrm{IN}_{2} \geq 2.1 \mathrm{~mA} \end{aligned}$ | $\begin{aligned} & 3 \\ & 6 \\ & 9 \end{aligned}$ | $\begin{aligned} & 3.6 \\ & 6.8 \\ & 10 \end{aligned}$ | $\begin{aligned} & 4.3 \\ & 8.6 \\ & 12.9 \end{aligned}$ | $v$ $v$ $v$ |
| $V_{T-}$ | Negative-Going Threshold Voltage at Osc and KBM Inputs | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \quad I_{\mathrm{N}} \geq 0.7 \mathrm{~mA} \\ & V_{C C}=10 \mathrm{~V}, \quad I_{\mathrm{N}} \geq 1.4 \mathrm{~mA} \\ & V_{C C}=15 \mathrm{~V}, \quad I_{I N} \geq 2.1 \mathrm{~mA} \end{aligned}$ | $\begin{aligned} & 0.7 \\ & 1.4 \\ & 2.1 \end{aligned}$ | $\begin{aligned} & 1.4 \\ & 3.2 \\ & 5 \end{aligned}$ | $\begin{aligned} & 2 \\ & 4 \\ & 6 \end{aligned}$ | v v v |
| $V_{I N(1)}$ | Logical "1" Input Voltage, Except Osc and KBM Inputs | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \\ & V_{C C}=10 \mathrm{~V}, \\ & V_{C C}=15 \mathrm{~V}, \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8 \\ & 12.5 \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9 \\ & 13.5 \end{aligned}$ |  | $v$ $v$ $v$ |
| $V_{I N}(0)$ | Logical "0" Input Voltage, Except Osc and KBM Inputs | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \\ & V_{C C}=10 \mathrm{~V}, \\ & V_{C C}=15 \mathrm{~V}, \end{aligned}$ |  | $\begin{aligned} & 0.5 \\ & 1 \\ & 1.5 \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 2 \\ & 2.5 \end{aligned}$ | V v v |
| $I_{r p}$ | Row Pull-Up Current at Y1, Y2, Y3, Y4 and Y5 Inputs | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \quad V_{I N}=0.1 V_{C C} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & -2 \\ & -10 \\ & -22 \end{aligned}$ | $\begin{aligned} & -5 \\ & -20 \\ & -45 \end{aligned}$ | $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ $\mu \mathrm{A}$ |
| VOUT(1) | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \quad I_{O}=-10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & V_{C C}=15 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9 \\ & 13.5 \end{aligned}$ |  |  | V V V |
| VOUT(0) | Logical " 0 " Output Voltage | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \quad I_{O}=10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=10 \mu \mathrm{~A} \\ & V_{C C}=15 \mathrm{~V}, I_{O}=10 \mu \mathrm{~A} \end{aligned}$ |  | , | $\begin{aligned} & 0.5 \\ & 1 \\ & 1.5 \end{aligned}$ | V v v |
| $\mathrm{R}_{\text {on }}$ | Column "ON" Resistance at X1, X2, X3 and X4 Outputs | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V}, \\ & V_{C C}=15 \mathrm{~V}, \quad V_{O}=1.5 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 500 \\ & 300 \\ & 200 \end{aligned}$ | $\begin{aligned} & 1400 \\ & 700 \\ & 500 \end{aligned}$ | $\begin{aligned} & \Omega \\ & \Omega \\ & \Omega \end{aligned}$ |
| ICC | Supply Current | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \quad \text { Osc at } 0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.55 \\ & 1.1 \\ & 1.7 \end{aligned}$ | $\begin{aligned} & 1.1 \\ & 1.9 \\ & 2.6 \end{aligned}$ | mA <br> mA <br> mA |
| $\operatorname{IIN(1)}$ | Logical "1" Input Current at Output Enable | $V_{C C}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| InN(0) | Logical " 0 " Input Current at Output Enable | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| CMOS/LPTTL INTERFACE |  |  |  |  |  |  |
| VIN(1) <br> Vin(0) | Logical "1" Input Voltage, Except Osc and KBM Inputs <br> Logical "0" Input Voltage, Except Osc and KBM Inputs | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \\ & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & v_{\mathrm{CC}^{-1}}{ }^{1.5} \\ & \mathrm{v}_{\mathrm{CC}}-1.5 \end{aligned}$ |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | V V v v |
| $\mathrm{V}_{\text {OUT }}(1)$ | Logical "1" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{C C}=4.5 \mathrm{~V} \\ & 1 \mathrm{O}=-360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{C C}=4.75 \mathrm{~V} \\ & 1 \mathrm{O}=-360 \mu \mathrm{~A} \end{aligned}$ | 2.4 <br> 2.4 |  | , | V v |
| $\mathrm{V}_{\text {OUT }}(0)$ | Logical " 0 " Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{C C}=4.5 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ |  |  | $0.4$ <br> 0.4 | V v |

## DC Electrical Characteristics (Contd.)



## AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd}} \mathrm{C}^{\text {t }}$ pd1 | Propagation Delay Time to Logical " 0 " or Logical " 1 " from D.A. | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, (Figure 1) |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ |  | 60 | 150 | ns |
|  |  | $V_{C C}=10 \mathrm{~V}$ |  | 35 | 80 | ns |
|  |  | $V_{C C}=15 \mathrm{~V}$ |  | 25 | 60 | ns |
| ${ }^{\text {O }} \mathrm{H}, \mathrm{t} 1 \mathrm{H}$ | Propagation Delay Time from Logical " 0 " or Logical " 1 " into High Impedance State | $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=10 \mathrm{pF}$ (Figure 2) |  |  |  |  |
|  |  | $V_{C C}=5 \mathrm{~V} \quad \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}$ |  | 80 | 200 | ns |
|  |  | $V_{C C}=10 \mathrm{VCL}=10 \mathrm{pF}$ |  | 65 | 150 | ns |
|  |  | $V_{C C}=15 \mathrm{~V}$ |  | 50 | 110 | ns |
|  | Propagation Delay Time from | $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, (Figure 2) |  |  |  |  |
|  | High Impedance State to a | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V} \quad \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}$ |  | 100 | 250 | ns |
|  | Logical " 0 " or Logical " 1 " | $V_{C C}=10 \mathrm{~V} C_{L}=50 \mathrm{pF}$ |  | 55 | 125 | ns |
|  |  | $V_{C C}=15 \mathrm{~V}$ |  | 40 | 90 | ns |
| CIN | Input Capacitance | Any Input, (Note 2) |  | 5 | 7.5 | pF |
| COUT | TRI-STATE Output Capacitance | Any Output, (Note 2) |  | 10 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.

## Switching Time Waveforms


$T 1 \simeq T 2 \approx R C, T 3 \approx 0.7 R C$ where $R \simeq 10 k$ and $C$ is external capacitor at KBM input.


Block Diagram


## Truth Table


*Omit for MM54C922/MM74C922

## Typical Performance Characteristics



Typical Ron vs VOUT at Any $X$ Output



Typical Applications

Typical Debounce Period vs $\mathrm{C}_{\text {KBM }}$


Synchronous Data Entry Onto Bus (MM74C922)


Outputs are enabled when valid entry is made and go into TRI-STATE when key is released.

Asynchronous Data Entry Onto Bus (MM74C922)

## Keyboard Suppliers

Mini Key Series KL Digitran Company Pasadena, California

Computronics Engineering 7235 Hollywood Blvd Hollywood, California 90046


Outputs are in TRI-STATE until key is pressed, then data is placed on bus. When key is released, outputs return to TRI-STATE.

Note 3: The keyboard may be synchronously scanned by omitting the capacitor at osc. and driving osc. directly if the system clock rate is lower than 10 kHz .


## Theory of Operation

The MM74C922/MM74C923 Keyboard Encoders implement all the logic necessary to interface a 16 or 20 SPST key switch matrix to a digital system. The encoder will convert a key switch closer to a 4(MM74C922) or 5(MM74C923) bit nibble. The designer can control both the keyboard scan rate and the key debounce period by altering the oscillator capacitor, $\mathrm{C}_{\text {OSE }}$, and the key bounce mask capacitor, $\mathrm{C}_{\text {MSk }}$. Thus, the MM74C922/ MM47C923's performance can be optimized for many keyboards.
The keyboard encoders connect to a switch matrix that is 4 rows by 4 columns (MM74C922) or 5 rows by 4 columns (MM74C923). When no keys are depressed, the row inputs are pulled high by internal pull-ups and the column outputs sequentially output a logic " 0 ". These outputs are open drain and are therefore low for $25 \%$ of the time and otherwise off. The column scan rate is controlled by the oscillator input, which consists of a Schmitt trigger oscillator, a 2-bit counter, and a 2-4-bit decoder.

When a key is depressed, key 0 , for example, nothing will happen when the $X 1$ input is off, since $Y 1$ will remain high. When the X 1 column is scanned, X 1 goes low and Y1 will go low. This disables the counter and keeps X 1 low. Y1 going low also initiates the key bounce circuit
timing and locks out the other $Y$ inputs. The key code to be outputted is a combination of the frozen counter value and the decoded $Y$ inputs. Once the key bounce circuit times out, the data is latched, and the Data Available (DAV) output goes high.

If, during the key closure the switch bounces, Y1 input will go high again, restarting the scan and resetting the key bounce circuitry. The key may bounce several times, but as soon as the switch stays low for a debounce period, the closure is assumed valid and the data is latched.

A key may also bounce when it is released. To ensure that the encoder does not recognize this bounce as another key clósure, the debounce circuit must time out before another closure is recognized.

The two key roll over feature can be illustrated by assuming a key is depressed, and then a second key is depressed. Since all scanning has stopped, and all other $Y$ inputs are disabled, the second key is not recognized until the first key is lifted and the key bounce circuitry has reset.

The output latches feed TRI-STATE®, which are enabled when the Output Enable $(\overline{\mathrm{OE}})$ input is taken low.

National Semiconductor

## MM74C925, MM74C926, MM74C927, MM74C928 4-Digit Counters with Multiplexed 7-Segment Output Drivers

## General Description

These CMOS counters consist of a 4 -digit counter, an internal output latch, NPN output sourcing drivers for a 7 -segment display, and an internal multiplexing circuitry with four multiplexing outputs. The multiplexing circuit has its own free-running oscillator, and requires no external clock. The counters advance on negative edge of clock. A high signal on the Reset input will reset the counter to zero, and reset the carryout low. A low signial on the Latch Enable input will latch the number in the counters into the internal output latches. A high signal on Display Select input will select the number in the counter to be displayed; a low level signal on the Display Select will select the number in the output latch to be displayed.

The MM74C925 is a 4-decade counter and has Latch Enable, Clock and Reset inputs.

The MM74C926 is like the MM74C925 except that it has a display select and a carry-out used for cascading counters. The carry-out signal goes high at 6000, goes back low at 0000.

The MM74C927 is like the MM74C926 except the second most significant digit divides by 6 rather than 10. Thus, if the clock input frequency is 10 Hz , the display would read tenths of seconds and minutes (i.e., 9:59.9).

The MM74C928 is like the MM74C926 except the most significant digit divides by 2 rather than 10 and the
carry-out is an overflow indicator which is high at 2000, and it goes back low only when the counter is reset. Thus, this is a $31 / 2$-digit counter.

## Features

- Wide supply voltage range

3 V to 6 V

- Guaranteed noise margin
- High noise immunity
0.45 V CC (typ.)
a High segment sourcing current
40 mA
$@ V_{c c}-1.6 \mathrm{~V}, V_{c c}=5 \mathrm{~V}$
- Internal multiplexing circuitry


## Design Considerations

Segment resistors are desirable to minimize power dissipation and chip heating. The DS75492 serves as a good digit driver when it is desired to drive bright displays. When using this driver with a 5 V supply at room temperature, the display can be driven without segment resistors to full illumination. The user must use caution in this mode however, to prevent overheating of the device by using too high a supply voltage or by operating at high ambient temperatures.

The input protection circuitry consists of a series resistor, and a diode to ground. Thus input signals exceeding $\mathrm{V}_{\mathrm{cc}}$ will not be clamped. This input signal should not be allowed to exceed 15 V .

## Connection Diagram

Dual-In-Line Package MM74C925


## Functional Description

| Reset | - Asynchronous, active high |
| :--- | :--- |
| Display Select | High, displays output of counter <br> Low, displays output of latch |
| Latch Enable | High, flow through condition <br> Low, latch condition |
| Clock | - Negative edge sensitive |

## Absolute Maximum Ratings (Note 1)

Voltage at Any Output Pin
Voltage at Any Input Pin
Operating Temperature Range. ( $T_{A}$ )
Storage Temperature Range
Package Dissipation
Operating $\mathrm{V}_{\mathrm{cc}}$ Range
$V_{c c}$
Lead Temperature (Soldering, 10 seconds)

Gnd -0.3 V to $\mathrm{V}_{\mathrm{cc}}+0.3 \mathrm{~V}$
Gnd -0.3 V to +15 V
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
Refer to $P_{D(M A X)}$ vs $T_{A}$ Graph
3 V to 6 V
6.5 V
${ }^{\circ}$ DC Electrical Characteristics Min/max limits apply at $-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{j}} \leq+85^{\circ} \mathrm{C}$, unless otherwise noted.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS TO CMOS |  |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\mathrm{V}_{\mathrm{cc}}=5.0 \mathrm{~V}$ | 3.5 |  |  | V |
| $V_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\mathrm{V}_{\mathrm{cc}}=5.0 \mathrm{~V}$ |  |  | 1.5 | $v$ |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage (Carry-out and Digit Output Only) | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A}$ | 4.5 |  |  | V |
| $V_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\mathrm{V}_{\mathrm{cc}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=10 \mu \mathrm{~A}$ |  |  | 0.5 | v |
| $I_{\text {IN(1) }}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {in(0) }}$ | Logical ' 0 ' Input Current | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | $-1.0$ | -0.005 |  | $\mu \mathrm{A}$ |
| Icc | Supply Current | $\begin{aligned} & \mathrm{V}_{\mathrm{cC}}=5.0 \mathrm{~V}, \text { Outputs Open Circuit, } \\ & \mathrm{V}_{\mathrm{IN}}=0 \mathrm{~V} \text { or } 5 \mathrm{~V} \end{aligned}$ |  | 20 | 1000 | $\mu \mathrm{A}$ |

CMOS/LPTTL INTERFACE

| $V_{1 N(1)}{ }^{*}$ | Logical " 1 " Input Voltage | $\mathrm{V}_{\mathrm{cc}}=4.75 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{cc}}$-1.5 |  |  | V |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\mathrm{V}_{\mathrm{cc}}=4.75 \mathrm{~V}$ |  |  | 0.8 | $v$ |
| $V_{\text {OUT(1) }}$ | Logical " " " Output Voltage (Carry-Out and Digit Output Only) | $\begin{aligned} & \mathrm{V}_{\mathrm{Cc}}=4.75 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ | 2.4 |  |  | v |
| $V_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{cc}}=4.75 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \end{aligned}$ |  |  | 0.4 | v |
| OUTPUT DRIVE |  |  |  |  |  |  |
| $V_{\text {Out }}$ | Output Voltage (Segment Sourcing Output) | $\begin{aligned} & \mathrm{I}_{\text {OUT }}=-65 \mathrm{~mA}, \mathrm{~V}_{\mathrm{cc}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{j}}=25^{\circ} \mathrm{C} \\ & \mathrm{I}_{\text {OUT }}=-40 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}\left\{\begin{array}{l} \mathrm{T}_{\mathrm{j}}=100^{\circ} \mathrm{C} \\ \mathrm{~T}_{\mathrm{j}}=150^{\circ} \mathrm{C} \end{array}\right. \end{aligned}$ | $\left\|\begin{array}{l} \mathrm{v}_{\mathrm{cc}}-1.6 \\ \mathrm{v}_{\mathrm{cc}}-2 \end{array}\right\|$ | $\begin{aligned} & \mathrm{v}_{\mathrm{cc}}-1.3 \\ & \mathrm{~V}_{\mathrm{cc}}-1.2 \\ & \mathrm{v}_{\mathrm{cc}}-1.4 \end{aligned}$ |  | V V v |
| $\mathrm{R}_{\text {ON }}$ | Output Resistance (Segment Sourcing Output) | $\begin{aligned} & \text { I OUT }=-65 \mathrm{~mA}, V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{j}}=25^{\circ} \mathrm{C} \\ & \text { I OUT }=-40 \mathrm{~mA}, V_{C C}=5 \mathrm{~V}, \begin{array}{l} T_{j}=100^{\circ} \mathrm{C} \\ T_{j}=150^{\circ} \mathrm{C} \end{array} \end{aligned}$ |  | $\begin{aligned} & 20 \\ & 30 \\ & 35 \end{aligned}$ | $\begin{aligned} & 40 \\ & 50 \end{aligned}$ | $\Omega$ $\Omega$ $\Omega$ |
|  | Output Resistance (Segment Output) Temperature Coefficient |  |  | 0.6 | 0.8 | \% ${ }^{\circ} \mathrm{C}$ |
| Isource | Output Source Current (Digit Output) | $\mathrm{V}_{\text {cC }}=4.75 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.75 \mathrm{~V}, \mathrm{~T}_{\mathrm{j}}=150^{\circ} \mathrm{C}$ | -1 | -2 |  | mA |
| Isource | Output Source Current (Carry-out) | $V_{\text {cc }}=5 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | -1.75 | $-3.3$ |  | mA |
| $I_{\text {sink }}$ | Output Sink Current (All Outputs) | $V_{\text {cc }}=5 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=V_{\text {cc }}, T_{j}=25^{\circ} \mathrm{C}$ | 1.75 | 3.6 |  | mA |
| $\theta_{\text {jA }}$ | Thermal Resistance | MM74C925 (Note 4) MM74C926, MM74C927, MM74C928 |  | $\begin{aligned} & 75 \\ & 70 \\ & \hline \end{aligned}$ | $\begin{aligned} & 100 \\ & 90 \end{aligned}$ | $\begin{aligned} & { }^{\circ} \mathrm{C} / \mathrm{w} \\ & { }^{\circ} \mathrm{C} / \mathrm{w} \end{aligned}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: CPD determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note, AN-90.
Note 4: $\theta_{\mathrm{jA}}$ measured in free-air with device soldered into printed circuit board.

AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ ，unless otherwise noted

|  | PARAMETER | CONDITIONS |  | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $f_{\text {MAX }}$ | Maximum Clock Frequency | $V_{c c}=5.0 \mathrm{~V},$ <br> Square Wave Clock | $\begin{aligned} & \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{j}}=100^{\circ} \mathrm{C} \end{aligned}$ | $\begin{aligned} & 2 \\ & 1.5 \end{aligned}$ | $\begin{aligned} & 4 \\ & 3 \end{aligned}$ |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $t_{r}, t_{f}$ | Maximum Clock Rise or Fall Time | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  |  |  | 15 | $\mu \mathrm{s}$ |
| $t_{\text {WR }}$ | Reset Pulse Width | $V_{C C}=5.0 \mathrm{~V}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{i}}=100^{\circ} \mathrm{C} \end{aligned}$ | 250 320 | $\begin{aligned} & 100 \\ & 125 \end{aligned}$ |  | ns |
| $t_{\text {WLE }}$ | Latch Enable Pulse Width | $\mathrm{V}_{C C}=5.0 \mathrm{~V}$ | $\begin{aligned} T_{j} & =25^{\circ} \mathrm{C} \\ T_{i} & =100^{\circ} \mathrm{C} \end{aligned}$ | 250 320 | $\begin{aligned} & 100 \\ & 125 \end{aligned}$ |  | ns |
| ${ }^{\text {S SET }}$（CK，LE） | Clock to Latch Enable Set－Up Time | $V_{C C}=5.0 \mathrm{~V}$ | $\begin{aligned} & T_{j}=25^{\circ} \mathrm{C} \\ & T_{j}=100^{\circ} \mathrm{C} \end{aligned}$ | $\begin{aligned} & 2500 \\ & 3200 \end{aligned}$ | $\begin{aligned} & 1250 \\ & 1600 \end{aligned}$ |  | ns |
| $t_{\text {LR }}$ | Latch Enable to Reset Wait Time | $\mathrm{V}_{\mathrm{cc}}=5.0 \mathrm{~V}$ | $\begin{aligned} T_{j} & =25^{\circ} \mathrm{C} \\ T_{j} & =100^{\circ} \mathrm{C} \end{aligned}$ | 0 0 | $\begin{aligned} & -100 \\ & -100 \end{aligned}$ |  | ns |
| $\mathrm{t}_{\text {SET }}$（R，LE） | Reset to Latch Enable Set－Up Time | $\mathrm{V}_{\mathrm{Cc}}=5.0 \mathrm{~V}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{j}}=100^{\circ} \mathrm{C} \end{aligned}$ | $\begin{aligned} & 320 \\ & 400 \end{aligned}$ | $\begin{aligned} & 160 \\ & 200 \end{aligned}$ |  | ns |
| $f_{\text {Mux }}$ | Multiplexing Output Frequency | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  |  | 1000 |  | Hz |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Any Input（Note 2） |  |  | 5 |  | pF |

## Typical Performance Characteristics



## Logic and Block Diagrams



MM74C927



Note．$V_{D}=$ Voltage across digit driver．


Input Protection


Common Cathode LED Display


Segment Identification
ロ1コヨ4
5号7日 c／ede

## Switching Time Waveforms



## MM54C929／MM74C929，MM54C930／MM74C930 1024－Bit Static Silicon Gate CMOS RAMs

## General Description

The MM54C929／MM74C929 and MM54C930／MM74C930 $1024 \times 1$ random access read／write memories are manu－ factured using silicon－gate CMOS technology．These RAMs are specifically designed to operate from standard 54／74 TTL power supplies；all inputs and outputs are TTL compatible．Data output is the same polarity as data in－ put．Internal latches store the address inputs and data output．Chip select input $\overline{\mathrm{CS} 1}$ serves as a chip strobe， controlling address and data latching．The Data－In and Data－Out terminals can be tied together for common I／O applications．Complete address decoding， 3 －chip select functions（MM54C930／MM74C930）and TRI－STATE® out－ put allow easy memory expansion and organization． The MM54C929／MM74C929 differs from the MM54C930／ MM74C930 only in that $\overline{\mathrm{CS} 1}, \overline{\mathrm{CS} 2}$ and $\overline{\mathrm{CS} 3}$ are inter－ nally connected together，providing a single chip－select input $\overline{\mathrm{CS}}$ ．

TRI－STATE is a registered trademark of National Semiconductor Corp．

Versatility，high speed，and low power make these RAMs ideal elements for use in many microprocessor，mini－ computer and main－frame－memory applications．

## Features

－Fast access－ 250 ns max．
－TRI－STATE outputs
－Low power－ $10 \mu \mathrm{~A}$ max．standby
－On－chip registers
－Single 5 V supply
－Inputs and output TTL compatible
－Data retained with $V_{C C}$ as low as 2 V
－Can be operated common I／O

## MM54C932/MM74C932 Phase Comparator

## General Description

The MM74C932/MM54C932 consists of two independent output phase comparator circuits. The two phase comparators have a common signal input and a common comparator input. The signal input can be directly coupled for a large voltage signal, or capacitively coupled to the self-biasing amplifier at the signal input for a small voltage signal.

Phase comparator I, an exclusive-OR gate, provides a digital error signal (phase comp. I out) and maintains $90^{\circ}$ phase shifts at the VCO center frequency. Between signal input and comparator input (both at 50\% duty cycle), it may lock onto the signal input frequencies that are close to harmonics of the VCO center frequency.

Phase comparator II is an edge-controlled digital memory network. It provides a digital error signal (phase comp. Il out) and lock in signal (phase pulses) to indicate a locked condition and maintains a $0^{\circ}$ phase shift between signal input and comparator input.

## Features

- Wide supply voltage range
- Convenient mini-DIP package
- TRI-STATE ${ }^{\circledR}$ phase-comparator output (comparator II)
- 200 mV input voltage (signal in) sensitivity(typical)


## Block Diagram



## Connection Diagram



Absolute Maximum Ratings

Voltage at Any Pin
-0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
Operating Temperature Range
MM54C932
MM74C932
Storage Temperature Range
Package Dissipation
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
Absolute Maximum VCC
Lead Temperature (Soldering, 10 seconds)
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}^{\prime}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
3 V to 15 V
18 V
$300^{\circ} \mathrm{C}$

## DC Electrical Characteristics

| Parameter |  | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ICC | Quiescent Device Current | PIN $5=V_{C C}$, PIN $8=V_{C C}$, PIN 3 |  |  |  |  |
|  |  | $V_{C C}=5 \mathrm{~V}$ |  | 0.005 | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{C C}=10 \mathrm{~V}$ |  | 0.01 | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {CC }}=15 \mathrm{~V}$ |  | 0.015 | 600 | $\mu \mathrm{A}$ |
|  |  | PIN $5=\mathrm{V}_{\mathrm{CC}}$, PIN $8=$ Open, PIN $3=O V$ |  |  |  |  |
|  |  | $V_{C C}=5 \mathrm{~V}$ |  | 5 | 205 | $\mu \mathrm{A}$ |
|  |  | $V_{C C}=10 \mathrm{~V}$ |  | 20 | 710 | $\mu \mathrm{A}$ |
|  |  | $V_{C C}=15 \mathrm{~V}$ |  | 50 | 1800 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $V_{C C}=5 \mathrm{~V}$ |  | 0 | 0.05 | V |
|  |  | $V_{C C}=10 \mathrm{~V}$ |  | 0 | 0.05 | V |
|  |  | $V_{C C}=15 \mathrm{~V}$ |  | 0 | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{C C}=5 \mathrm{~V}$ | 4.95 | 5 |  | V |
|  |  | $V_{C C}=10 \mathrm{~V}$ | 9.95 | 10 |  | V |
|  |  | $V_{C C}=15 \mathrm{~V}$ | 14.95 | 15 |  | V |
| VIL | Low Level Input Voltage Comparator and Signal | $V_{C C}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 2.25 | 1.5 | $\checkmark$ |
|  |  | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 4.5 | 3.0 | V |
|  |  | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 6.25 | 4.0 | V |
| $\mathrm{V}_{\text {IH }}$ | High Level Input Voltage | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 | 2.75 |  | V |
|  | Comparator and Signal | $V_{C C}=10 \mathrm{~V}, V_{O}=1 \mathrm{~V}$ or 9 V | 7.0 | 5.5 |  | V |
|  |  | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 | 8.25 |  | V |
| ${ }^{\prime} \mathrm{OL}$ | Low Level Output Current | $V_{C C}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | $0.36$ |  |  | $\mathrm{mA}$ |
|  |  | $V_{C C}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 0.9 | 2.25 |  | $\mathrm{mA}$ |
|  |  | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 2.4 | 8.8 |  | $m A$ |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{C C}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | $-0.36$ |  |  | $\mathrm{mA}$ |
|  |  | $V_{C C}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -0.9 | -2.25 |  | mA |
|  |  | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -2.4 | -8.8 |  | mA |
| IIN | Input Current | All Inputs Except Signal Input |  |  |  |  |
|  |  | $V_{C C}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V}$ |  | $-10-5$ | $-1.0$ | $\mu \mathrm{A}$ |
|  |  | $\mathrm{V}_{\text {CC }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | , $10-5$ | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{CIN}^{\text {IN }}$ | Input Capacitance | Any Input, (Note 3) |  | - | 7.5 | pF |
| $\mathrm{P}_{\text {T }}$ | Total Power Dissipation | $\begin{aligned} & f_{\mathrm{O}}=10 \mathrm{kHz}, \mathrm{R} 1=1 \mathrm{M} \Omega \\ & \mathrm{R} 2=\infty, \mathrm{VCO}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}} / 2 \end{aligned}$ |  |  |  |  |
|  |  | $V_{C C}=5 \mathrm{~V}$ |  | 0.07 |  | mW |
|  |  | $V_{C C}=10 \mathrm{~V}$ |  | 0.6 |  | mW |
|  |  | $\mathrm{V}_{\text {CC }}=15 \mathrm{~V}$ |  | 2.4 |  | mW |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

## Electrical Characteristics

|  | Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Phase Comparators |  |  |  |  |  |  |
| RIN | Input Resistance Signal Input | $V_{C C}=5 \mathrm{~V}$ | 1.0 | 3.0 |  | $\mathrm{M} \Omega$ |
|  |  | $V_{C C}=10 \mathrm{~V}$ | 0.2 | 0.7 |  | $\mathrm{M} \Omega$ |
|  |  | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ | 0.1 | 0.3 |  | $\mathrm{M} \Omega$ |
|  | Comparator Input | $V_{C C}=5 \mathrm{~V}$ |  | $10^{6}$ |  | $\mathrm{M} \Omega$ |
|  |  | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ |  | $10^{6}$ |  | $\mathrm{M} \Omega$ |
|  |  | $V_{C C}=15 \mathrm{~V}$ |  | $10^{6}$ |  | $\mathrm{M} \Omega$ |
|  | AC Coupled Signal Input Voltage Sensitivity | $\begin{aligned} & \text { CSERIES }=1000 \mathrm{pF} \\ & \mathrm{f}=50 \mathrm{kHz} \end{aligned}$ |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ |  | 200 | 400 | mV |
|  |  | $V_{C C}=10 \mathrm{~V}$ |  | 400 | 800 | mV |
|  |  | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 700 | 1400 | mV |

## Phase Comparator State Diagrams

| PHASE COMPARATOR I |  |  |
| :---: | :---: | :---: |
| INPUT STATE COMPARATOR <br> IN |  |  |
| PHASE COMP I OUT | 0 | 1 |



Figure 1.


Figure 2. Typical Waveform Employing Phase Comparator I in Locked Condition


Figure 3. Typical Waveform Employing Phase Comparator II in Locked Condition

## Typical Phase Locked Loop



## MM54C933/MM74C933 Address Bus Comparator

## General Description

The MM54C933/MM74C933 Bus Comparator compares two binary words of up to 7 bits in length, and determines whether they are equal (bit for bit). Both enable $(\overline{E N})$ inputs must be low to enable the comparison. The output, which is normally high, goes low when inputs $\mathrm{A}_{0}-\mathrm{A}_{6}$ and $\mathrm{B}_{0}-\mathrm{B}_{6}$ are equal.

The ' $A$ ' set of inputs is provided with latches which allow the inputs to flow through when ALE is high, and are latched when ALE is brought low.

## Features

- Silicon Gate CMOS technology used for high speed
- Wide supply voltage range 3-6V
- 2 active low enables for cascading and control
- One set of latched inputs for easy interfacing to multiplexed $\mu \mathrm{P}$ busses
- Active low output compatible with memory and $\mu \mathrm{P}$ peripherals


## Typical Applications

- Microprocessor Address/Data Bus decoders
- Equality detectors


## Logic and Connection Diagrams



## Absolute Maximum Ratings (Note 1)

Voltage at Any Pin
Operating Temperature Range

## MM54C933

MM74C933
Storage Temperature Range
Package Dissipation
Operating $V_{C C}$ Range
Absolute Maximum $\mathrm{V}_{\mathrm{CC}}$
Lead Temperature (Soldering, 10 seconds)
-0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
3.0 V to 6.0 V
7.0 V
$300^{\circ} \mathrm{C}$

DC Electrical Characteristics Min./max. limits apply across temperature range unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IH }}$ | Input High Voltage | $\mathrm{V}_{\text {CC }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  |  | v |
| $V_{\text {IL }}$ | Input Low Voltage | $\mathrm{V}_{\text {CC }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0.5 \mathrm{~V}$ or 4.5 V |  |  | 1.5 | v |
| $\mathrm{V}_{\mathrm{OH}}$ | Output High Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-1 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V} \text { or } 5.0 \mathrm{~V} \end{aligned}$ | 4.95 |  |  | v |
| $\mathrm{V}_{\text {OL }}$ | Output Low Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, I_{0}=1 \mu \mathrm{~A} \\ & \mathrm{~V}_{\text {IN }}=0 \mathrm{~V} \text { or } 5.0 \mathrm{~V} \end{aligned}$ |  |  | 0.05 | v |
| IOH | Output High Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \mathrm{~V}_{I N}=0 \mathrm{~V} \text { or } 5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V} \end{aligned}$ | -2.0 |  |  | mA |
| IOL | Output Low Current | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{I N}=0 \mathrm{~V} \text { or } 5.0 \mathrm{~V} \\ & V_{\mathrm{O}}=0.4 \mathrm{~V} \end{aligned}$ | +2.0 |  |  | mA |
| $\mathrm{I}_{\mathbf{N}(1)}$ | Logical " 1 " Input Current | $\mathrm{V}_{\mathrm{CC}}=6.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{1 \times(0)}$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=6.0 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{cc}}$ | Supply Current | $V_{\text {CC }}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
| CMOS/LSTTL Interface (MM54C933: $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \pm 10 \%$, MM74C933: $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \pm 5 \%$ ) |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IN}(1)}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{\mathrm{O}}=0.4 \mathrm{~V} \text { or } \mathrm{V}_{\mathrm{CC}}-0.4 \\ & \mathrm{I}_{\mathrm{O}}= \pm 10 \mu \mathrm{~A} \end{aligned}$ | $\mathrm{V}_{\mathrm{CC}}-1.5$ |  |  | v |
| $\mathrm{V}_{\mathrm{IN}(0)}$ | Logical "0" Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V} \text { or } \mathrm{V}_{\mathrm{CC}}-0.4 \\ & \mathrm{I}_{\mathrm{O}}= \pm 10 \mu \mathrm{~A} \end{aligned}$ |  |  | 0.8 | v |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=4.0 \mathrm{~V} \text { or } 1.0 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{O}}=-2.0 \mathrm{~mA} \end{aligned}$ | 2.4 |  |  | v |
| $V_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & V_{I_{N}}=4.0 \mathrm{~V} \text { or } 1.0 \mathrm{~V} \\ & I_{0}=+2.0 \mathrm{~mA} \end{aligned}$ |  |  | 0.4 | v |
| Output Drive (See 54C/74C Family Characteristics Data Sheet) |  |  |  |  |  |  |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 16 |  |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, V_{\text {OUT }}=V_{C C} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | 16 |  |  | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$, unless otherwise specified.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {PLH }}, \mathrm{t}_{\text {PHL }}$ | Propagation Delay A to OUT | $\begin{aligned} & \mathrm{ALE}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF} \\ & \mathrm{ALE}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=100 \mathrm{pF} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 60 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {PLH, }}, \mathrm{t}_{\text {PHL }}$ | Propagation Delay B to OUT | $\begin{aligned} & C_{L}=15 p F \\ & C_{L}=100 p F \end{aligned}$ |  | $\begin{aligned} & 40 \\ & 50 \end{aligned}$ |  | ns ns |
| $t_{\text {PLH }}, t_{\text {PHL }}$ | Propagation Delay $\overline{\mathrm{EN1}}$ or $\overline{\mathrm{EN} 2}$ to OUT | $\begin{aligned} & C_{L}=15 \mathrm{pF} \\ & \mathrm{C}_{\mathrm{L}}=100 \mathrm{pF} \end{aligned}$ |  | $\begin{aligned} & 10 \\ & 20 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {PLH }}, \mathrm{t}_{\text {PHL }}$ | Propagation Delay ALE to OUT | $\begin{aligned} & C_{L}=15 \mathrm{pF} \\ & C_{L}=100 \mathrm{pF} \end{aligned}$ |  | $\begin{aligned} & 30 \\ & 40 \end{aligned}$ |  | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{s}$ | Time prior to ALE that A must be present |  | - | 5.0 |  | ns |
| $t_{H}$ | Time after ALE that A must be present |  |  | 5.0 |  | ns |
| $t_{\text {w }}$ | Minimum ALE Pulse Width |  |  | 10 |  | ns |
| ${ }_{\text {t }}$ | Ourput Transition Time | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ |  | 10 |  | ns |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | (Note 2) |  | 10 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 3) |  | 100 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines that no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note, AN-90.

## Truth Tables

| EN1 or EN2 | $\mathbf{A}_{\mathbf{N}}$ | $\mathbf{B}_{\mathbf{N}}$ | $\overline{\mathrm{OUT}}$ |
| :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | 0 |
| 0 | 0 | 1 | 1 |
| 0 | 1 | 0 | 1 |
| 0 | 1 | 1 | 0 |
| 1 | X | X | 1 |


| ALE | Function |
| :---: | :--- |
| 0 | $A_{N}$ Inputs Latched |
| 1 | $A_{N}$ Inputs Flow-Through |

## Switching Time Waveforms



## MM54C941／MM74C941 Octal Buffers／Line Receivers／ Line Drivers with TRI－STATE ${ }^{\text {® }}$ Outputs

## General Description

These octal buffers and line drivers are monolithic com－ plementary MOS（CMOS）integrated circuits with TRI－ STATE ${ }^{\circledR}$ outputs．These outputs have been specially designed to drive highly capacitive loads such as bus－ oriented systems．These devices have a fan－out of 6 low power Schottky loads．When $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ inputs can accept true TTL high and low logic levels．

TRI－STATE is a registered trademark of National Semiconductor Corp．

## Features

－Wide supply voltage range（ 3 V to 15 V ）
－Low power consumption
－TTL compatibility（Improved on the inputs）
－High capacitive load
－TRI－STATE ${ }^{\oplus}$ outputs
－Input protection
－20－pin dual－in－line package
－High output drive

## Connection Diagram




Absolute Maximum Ratings (Note 1)<br>Voltage at Any Pin<br>Operating Temperature Range<br>MM54C941<br>MM74C941<br>Storage Temperature Range<br>Package Dissipation<br>Operating $\mathrm{V}_{\mathrm{CC}}$ Range<br>$V_{C C}$<br>Lead Temperature (Soldering, 10 seconds)<br>0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$<br>$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$<br>$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$<br>$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW<br>3.0 V to 15 V<br>18 V<br>$300^{\circ} \mathrm{C}$

DC Electrical Characteristics Min/max limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 2.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical " 0 " Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | 0.8 2.0 | V |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | V |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical " 0 " Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, 18=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{I}_{\operatorname{IN}(1)}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $I_{\text {IN(0) }}$ | Logical "0" Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| $I_{\text {cc }}$ | Supply Current | $V_{C C}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
|  | Tristate Leakage | $\mathrm{V}_{\text {CC }}=15 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V}$ or 15 V |  |  | $\pm 3.0$ | $\mu \mathrm{A}$ |
| CMOSITTL Interface |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{C}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & V_{C C}-2.5 \\ & V_{C C}-2.5 \end{aligned}$ |  |  | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical " 0 " Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {OUT(1) }}$ | Logical " 1 " Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-450 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-450 \mu \mathrm{~A} \\ & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-2.2 \mathrm{~mA} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-2.2 \mathrm{~mA} \end{aligned}$ | $\begin{gathered} \mathrm{V}_{\mathrm{CC}}-0.4 \\ \mathrm{~V}_{\mathrm{CC}}-0.4 \\ 2.4 \\ 2.4 \end{gathered}$ |  |  | $\begin{aligned} & v \\ & v \\ & v \\ & v \end{aligned}$ |
| $V_{\text {OUT(0) }}$ | Logical " 0 " Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+2.2 \mathrm{~mA} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+2.2 \mathrm{~mA} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |


| Output Drive (See 54C/74C Family Characteristics Data Sheet) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | -14.0 | -30.0 | mA |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | -36.0 | -70.0 | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink <br> Current ( N -Channel) | $\begin{aligned} & V_{\mathrm{VCC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | +12.0 | +20.0 | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | +48.0 | +70.0 | mA |

AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd} 1}, \mathrm{t}_{\mathrm{pd} 0}$ | Propagation Delay (Data IN TO OUT) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF} \end{aligned}$ |  | $\begin{aligned} & 70 \\ & 35 \\ & 90 \\ & 45 \end{aligned}$ | $\begin{gathered} 140 \\ 70 \\ 160 \\ 90 \end{gathered}$ | ns <br> ns <br> ns ns |
| $t_{\text {IH }}, \mathrm{t}_{\mathrm{OH}}$ | Propagation Delay Output Disable to Logic Level (from High Impedance State) (from a Logic Level) | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=210 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 100 \\ 55 \end{gathered}$ | $\begin{aligned} & 200 \\ & 110 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{H 1}, t_{\text {H0 }}$ | Propagation Delay Output Disable to Logic Level (from High Impedance State) | $\begin{aligned} & R_{\mathrm{L}}=1 \mathrm{k} \Omega, C_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 100 \\ 55 \end{gathered}$ | $\begin{aligned} & 200 \\ & 110 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {THL }}, t_{\text {tLH }}$ | Transition Time | $\begin{aligned} & V_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=150 \mathrm{pF} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 30 \\ & 80 \\ & 50 \end{aligned}$ | $\begin{gathered} 100 \\ 60 \\ 160 \\ 100 \end{gathered}$ | ns ns ns ns |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance (Output Enabled per Buffer) <br> (Output Disabled per Buffer) | (See Note 3) |  | $\begin{gathered} 100 \\ 10 \end{gathered}$ |  | $\begin{aligned} & \mathrm{pF} \\ & \mathrm{pF} \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance <br> (Any Input) | (See Note 2) $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 10 |  | pF |
| $\mathrm{C}_{0}$ | (Output Capacitance) (Output Disabled) | $\begin{aligned} & V_{I N}=0 \mathrm{v}, \mathrm{f}=1 \mathrm{MHz}, \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 10 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Truth Table

| OD1 | OD2 | Input | Output |
| :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | 0 |
| 0 | 0 | 1 | 1 |
| 0 | 1 | X | Z |
| 1 | 0 | X | Z |
| 1 | 1 | X | Z |

$$
\begin{aligned}
& 1=\text { High } \\
& 0=\text { Low } \\
& X=\text { Don't Care } \\
& Z=\text { TRI-STATE }{ }^{\oplus}
\end{aligned}
$$




Propagation Delay vs. Load Capacitance

$\Delta$ tpD per pF of Load Capacitance


Applications


## AC Test Circuits and Switching Time Waveforms

$\mathbf{t}_{\mathbf{p d} \mathbf{0}}, \mathrm{t}_{\mathrm{pd}} \mathbf{1}$


CMOS to CMOS



NOTE: $\mathrm{V}_{\text {OH }}$ IS DEFINED AS THE DC OUTPUT High VOLTAGE WHEN THE DEVICE IS LOADED WITH A $1 \mathrm{k} \Omega$ RESISTOR TO GROUND.



NOTE: $V_{\text {ol }}$ IS DEFINED AS the dC OUTPUT LOW VOltage WHEN THE DEVICE IS LOADED WITH A $1 \mathrm{k} \Omega$ RESISTOR TO $\mathrm{V}_{\mathrm{cc}}$.
Note: Delays measured with input $t_{r}, t_{4} \leq 20$ ns

## MM74C945, MM74C947 4-Digit Up/Down Counter/Latch/Decoder Driver

## General Description

The MM74C945, MM74C947 are 4-digit counters for directly driving LCD displays. The MM74C945 contains a 4-decade up/down counter, output latches, counter/latch select multiplexer and 7 -segment decoders. Also inćluded are the backplane oscillator/driver, segment drivers and display blanking circuitry.
The MM74C947 differs from the MM74C945 in that it has no counter/latch multiplexer, but provides true leading zero blanking. All leading zeroes are automatically blanked except the least significant digit, which can be optionally blanked.

Both devices provide 28 -segment outputs to drive a 4-digit display. Segment and backplane waveforms are generated internally, but can also be slaved to an external signal. This facilitates cascading of multiple displays.

## Features

- 4-decade up/down count
- Direct 4-digit drive for high contrast and long display life
- Carry/borrow out for cascading counters
- Schmitt trigger clock input
- MM74C945 has display select to allow viewing of counter or latch
- Store and reset inputs allow operation as frequency or period counter
( ${ }^{\text {D }}$ M 74 C947 has true ripple blanking; least significant digit may be optionally blanked


## Connection Diagrams



Voltage at Any Pin
Operating Temperature Range MM74C945／MM74C947

Storage Temperature Range

Package Dissipation
500 mW
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
Absolute Maximum $V_{C C}$
Lead Temperature（Soldering， 10 seconds）
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$

| Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS TO CMOS |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{T}+}$ Positive Going Threshold Voltage（Clock Only） | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ |  | 3.3 |  | V |
| $V_{T-}$ Negative Going Threshold Voltage（Clock Only） | $V_{C C}=5 \mathrm{~V}$ |  | 1.8 |  | V |
| Hysteresis（ $\mathrm{V}_{\mathrm{T}+}-\mathrm{V}_{\mathrm{T}-}$ ） （Clock Only） | $V_{C C}=5 \mathrm{~V}$ |  | 1.5 |  | V |
| Logical＂1＂Input Voltage（ $\mathrm{V}_{\text {IN（1）}}$ ） （All Inputs Except Clock） | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ | 3.5 |  |  | V |
| Logical＂ 0 ＂Input Voltage（ $\mathrm{V}_{\mathrm{IN}(0)}$ ） <br> （All Inputs Except Clock） | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ |  |  | 1.5 | V |
| Logical＂1＂Output Voltage （ $\mathrm{V}_{\text {OUT（1）}}$ ）（LZO and Carry） | $\mathrm{V}_{C C}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A}$ | 4.5 |  |  | V |
| Logical＂0＂Output Voltage （ $\mathrm{V}_{\text {OUT（0）}}$ ）（LZO and Carry） | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A}$ |  |  | 0.5 | V |
| Logical＂1＂Input Current（ $\left.1_{\mathbb{I N}_{(1)}}\right)$ （Note 2） | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=5 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| Logical＂ 0 ＂Input Current $\left(1_{I_{N}(0)}\right)$ （Note 2） | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | －1．0 | －0．005 |  | $\mu \mathrm{A}$ |
| Oscillator Input Current（ $\mathrm{I}_{\text {OLL }}$ ） | $V_{C C}=5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V} / 5 \mathrm{~V}$ |  | $\pm 2$ |  | $\mu \mathrm{A}$ |
| Supply Current（1）${ }_{\text {CC }}$ ）（Note 3） | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V} / 5 \mathrm{~V}$ |  | 10 |  | $\mu \mathrm{A}$ |
| CMOS／LPTTL INTERFACE |  |  |  |  |  |
| Logical＂1＂Input Voltage $\left(\mathrm{V}_{\text {IN（1）}}\right)$（Clock Input） |  | 4.3 |  |  | V |
| Logical＂ 0 ＂Input Voltage $\left(\mathrm{V}_{\text {IN }(0)}\right)$（Clock Input） | $V_{C C}=5 V$ |  |  | 0.7 | V |
| Logical＂1＂Input Voltage （ $\mathrm{V}_{\text {IN（1）}}$ ）（All Inputs Except Clock） | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ | $\mathrm{V}_{C C}-1.5 \mathrm{~V}$ |  |  | V |
| Logical＂0＂Input Voltage （ $\mathrm{V}_{\text {IN }(0)}$ ）（All Inputs Except Clock） | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ |  |  | 0.4 | V |
| Logical＂1＂Output Voltage （ $\mathrm{V}_{\text {OUT（1）}}$ ）（LZO and Carry） | $V_{C C}=4.75 \mathrm{~V}, I_{\mathrm{O}}=-360 \mu \mathrm{~A}$ | 2.4 |  |  | V |
| Logical＂0＂Output Voltage （ $\mathrm{V}_{\text {OUt（0）}}$ ）（LZO and Carry） | $\mathrm{V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A}$ |  |  | 0.4 | V |
| OUTPUT DRIVE |  |  |  |  |  |
| Output Source Current （ISOURCE）（LZO and Carry） | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | ． | 2.6 |  | mA |
| Output Sink Current （I SINK ）（LZO and Carry） | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 2.8 |  | mA |
| Output Source Current （I SOURCE）（Segment Outputs） | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 1.9 |  | mA |
| Output Sink Current （I ${ }_{\text {SINK }}$ ）（Segment Output） | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | ． | 1.6 |  | mA |
| Output Source Current （I ${ }_{\text {SOURCE }}$ ）（Backplane Output） | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 16.0 |  | mA |
| Output Sink Current （I $\mathrm{I}_{\text {INK }}$ ）（Backplane Output） | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 13.0 |  | mA |

AC Electrical Characteristics $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

|  | Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Clock to Carry |  |  |  |  |  |
| $f_{\text {MAX }}$ | Maximum Clock Frequency | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  | 2 |  | MHz |
| $\mathrm{t}_{\mathrm{r},} \mathrm{t}_{\mathrm{f}}$ | Maximum Clock Rise or Fall Time | $V_{C C}=5.0 \mathrm{~V}$ |  |  | No Limit | $\mu \mathrm{S}$ |
| $t_{\text {WR }}$ | Reset Pulse Width | $V_{C C}=5.0 \mathrm{~V}$ |  |  |  | ns |
| $t_{\text {ws }}$ | Store Pulse Width | $V_{C C}=5.0 \mathrm{~V}$ |  |  | - | ns |
| $\left.\mathrm{t}_{\text {SET(CK, }} \mathrm{s}\right)$ | Clock to Store Set-Up Time | $V_{C C}=5.0 \mathrm{~V}$ |  |  |  | ns |
| $t_{\text {SR }}$ | Store to Reset Wait Time | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  |  |  | ns |
| $t_{\text {SET }}$ R, S) | Reset to Store Set-Up Time | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  |  |  | ns |
| $\mathrm{t}_{\text {SET }(\mathrm{E}, \mathrm{s})}$ | Enable to Store Set-Up Time | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  |  |  | ns |
| $t_{\text {RR }}$ | Reset Removal | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  |  |  | ns |
| $t_{\text {pdc }}$ | Propagation Delay Reset to Carry | $V_{C C}=5.0 \mathrm{~V}$ |  |  |  | ns |
| $f_{B P}$ | Backplane Output Frequency | Pin 36 Floating |  | 125 |  | Hz |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Logic Inputs (Note 2) |  | 5 |  | pF |
| $\mathrm{t}_{\mathrm{ffs}}$ | Segment Rise/Fall Time | $\mathrm{C}_{\text {load }}=200 \mathrm{pF}$ |  | 0.5 |  | $\mu \mathrm{S}$ |
| $t_{\text {rfb }}$ | Backplane Rise/Fall Time | $\mathrm{C}_{\text {load }}=5000 \mathrm{pF}$ |  | 1.5 |  | $\mu \mathrm{S}$ |
| $\mathrm{f}_{\text {osc }}$ | Oscillator Frequency | Pin 36 Floating |  | 16 |  | kHz |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Does not apply to backplane and oscillator pins.
Note 3: Display blanked. See test circuit.

## AC Waveforms



Segment Identification


## Test Circuit



[^6]

MM74C947


## Pin Description

Backplane In/Out - When the oscillator input is grounded this pin is an input allowing an external device to generate a backplane waveform. When the oscillator input is left open this pin is an output supplying backplane drive for the display.
Oscillator-The oscillator frequency may be lowered by tying a capacitor to this pin. On the MM74C947 when the oscillator pin is open the LSD is inhibited from blanking when leading zero blanking is enabled. If this pin is grounded the backplanes on both parts become inputs, slaving the device to an external backplane.
Store-This input controls the on-chip latches. When low, the latches are in flow-through mode (latch outputs follow counter), but when taken high, the data on the counter outputs are stored in the latches.
$\overline{\text { Reset }}$-When low, counters are reset to zero.
Clock-Advances counters on negative edge.
Enable-When low, halts counter operation.
Leading Zero Input (LZI)-(MM74C947) When high, enables leading zero blanking.

Leading Zero Output (LZO)—(MM74C947) This output goes high when the latch contents equal zero, LZ is high and the oscillator pin is open.

Blanking-(MM74C945) When high, blanks display.
Select-(MM74C945) When high, the contents of the counter are displayed. When low, the contents of the latch are displayed.
Carry - This output goes high when 9999 is reached (up) or 0000 is reached (down).
Up/Down-When high, the counter counts up. When low, the counter counts down.

A1-G1-Digit 1 segment outputs.
A2-G2-Digit 2 segment outputs.
A3-G3 - Digit 3 segment outputs.
A4-G4-Digit 4 segment outputs.

## Timing Diagrams



## Application Hints

## Display Circuitry Description

The MM74C945 and MM74C947 have 28 segment outputs capable of directly driving 4 digits of 7 segments. Both the segment and backplane drivers are designed to provide matched rise and fall times eliminating possible DC components in the driving waveforms which could degrade display life.

The backplane driver can be disabled by grounding the oscillator pin. This enables the segment output waveforms to be synchronized to an external signal applied to the backplane pin. This allows several devices to be driven by a single master backplane waveform which can be generated by another MM74C945, MM74C947 or an external oscillator. Thus single backplane displays with $8,12,16$, etc. digits can be driven by several counters. The maximum fanout of a master backplane driver is limited by its total capacitive load, which is the sum of the slaved backplane input capacitances and the display backplane capacitance. (The MM74C947 oscillator pin controls the least significant digit blanking as well.)

An on-board oscillator/divider generates the segment/ backplane waveforms. Its output frequency is typically 125 Hz , but may be slowed by connecting an external capacitor between the oscillator pin and ground. The oscillator pin may also be driven by an external waveform but the input low level must not go to ground or else the backplane pin will be put in the slave (input) mode.

## Counter Circuitry Description

The MM74C945, MM74C947 are 4-decade up/down counters. The direction of the count is controlled by the up/down input. A high level on this pin causes the counter to count up. The counter advances on the negative clock edge. The carry output is high for 1 clock period during a count of 9999 in up mode and also high during a count of 0000 in down mode. The carry is designed to enable cascading of several circuits in either ripple carry or synchronous modes.

Reset and Enable controls are provided to allow period and frequency measurements. The Reset control clears the counter when low and the Enable control disables counting when taken low.

The counter chain feeds a series of 4-bit flow-through latches. These latches enable the display to follow the counter when the Store input is low. When the Store pin is taken high the data on the counter outputs at this time become latched and the display will remain unchanged. (Assuming the latch display is selected on MM74C945.)

On the MM74C945 the latch outputs feed a multiplexer which selects either the latch outputs or counter outputs for display. This allows an intermediate count to be stored in the latches while the counter continues to be displayed. This is equivalent to a stopwatch lap feature.
The output of the MM74C945's multiplexer feeds a decoder which converts 4 -bit input to 7 -segment. A blank control into these decoders blanks the display.

## Application Hints (Continued)

On the MM74C947 the latch outputs feed the decoders directly, but these decoders have a special ripple blanking capability that enables all leading zeroes except the least significant digit (LSD) to be blanked, even when counters are cascaded. Thus when the entire counter reads zero, instead of blanking all digits, the LSD will remain on. (When multiple counters are cascaded, all except the least signif-
icant counter will blank entirely on zeroes.) This feature is properly implemented by configuring the least significant device as the master (oscillator pin ungrounded) thereby inhibiting LSD blanking.

The outputs of the decoders for both devices control the segment drivers which in turn enable display operation.

## Typical Applications

Ripple Carry Cascading-MM74C945



[^7]
## Typical Applications (Continued)

Ripple Cascading—MM74C947


Synchronous Cascading-MM74C947


[^8]
## MM74C946 4½-Digit Counter/Decoderl Driver for LCD Displays

## General Description

The MM74C946 is a $41 / 2$-digit CMOS counter which contains a counter chain, decoders, output latches, LCD segment drivers, count inhibit and backplane oscillator/driver circuitry. This device also contains leading zero blanking and a carry output to increase flexibility and facilitate cascading of multiple 4 -digit sections.

This device provides 29 segment outputs to drive a standard $41 / 2$-digit liquid crystal display. An on-chip backplane oscillator/driver is also provided. This can be disabled by grounding the oscillator pin, thus allowing the device to be slaved to an external backplane signal via the backplane pin.

## Features

■ Low power operation-less than $100 \mu \mathrm{~W}$ quiescent

- Direct $41 / 2$-digit 7 -segment display drive for higher contrast and long display life
- Pin compatible to Intersil's ICM7224
- Store and $\overline{\text { Reset }}$ inputs permit operation as frequency or period counter
- True count inhibit disables first counter stage
- Carry output for cascading 4-digit blocks
- Schmitt trigger on the clock input allows operation in noisy environments or with slowly changing inputs
- Leading zero blanking input and output for correct leading zero blanking with cascaded devices
■ On-chip backplane oscillator/driver which can be disabled to permit slaving of multiple devices to an external backplane signal


## Connection Diagram

Dual-In-Line Package


Absolute Maximum Ratings (Note 1)<br>Voltage at Any Pin<br>Operating Temperature Range MM74C946<br>Storage Temperature Range<br>Package Dissipation<br>Operating $V_{C C}$ Range<br>Absolute Maximum $V_{C C}$<br>Lead Temperature (Soldering, 10 seconds)<br>-0.3 V to $\mathrm{V}_{\mathrm{cc}}+0.3 \mathrm{~V}$<br>$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$<br>$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$<br>500 mW<br>3.0 V to 6.0 V<br>6.5 V<br>$300^{\circ} \mathrm{C}$

DC Electrical Characteristics Min/max limits apply across temperature range, unless otherwise noted.

| Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS TO CMOS |  |  |  |  |  |
| $V_{T+}$ Positive Going Threshold Voltage (Clock Input) | $V_{C C}=5 \mathrm{~V}$ |  | 3.3 |  | V |
| $V_{T}$ - Negative Going Threshold Voltage (Clock Input) | $V_{C C}=5 \mathrm{~V}$ |  | 1.8 |  | V |
| Hysteresis ( $\mathrm{V}_{\mathrm{T}+}-\mathrm{V}_{\mathrm{T}-}$ ) <br> (Clock Input) | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ |  | 1.5 |  | V |
| Logical " 1 " Input Voltage ( $\left.\mathrm{V}_{\operatorname{IN}(1)}\right)$ (All Inputs Except Clock Input) | $V_{C C}=5 \mathrm{~V}$ | 3.5 |  |  | V |
| Logical "0" Input Voltage ( $\mathrm{V}_{\mathrm{IN}(0)}$ ) <br> (All Inputs Except Clock Input) | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ |  |  | 1.5 | V |
| Logical "1" Output Voltage ( $\mathrm{V}_{\text {OUT(1) }}$ ) (LZO and Carry) | $V_{C C}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A}$ | 4.5 |  |  | V |
| Logical "0" Output Voltage ( $\mathrm{V}_{\text {OUT(O) }}$ ) (LZO and Carry) | $\mathrm{V}_{C C}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+10 \mu \mathrm{~A}$ |  |  | 0.5 | V |
| Clock Input Current $\left\|\mathrm{I}_{\mathbf{I N}}\right\|$ | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=5 \mathrm{~V} / 0 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| Input Current @ Pins 29, 31, 33 and 34 (Note 2) | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V}$ | $-2.0$ |  | -25.0 | $\mu \mathrm{A}$ |
| Oscillator Pin Current ( $\mathrm{I}_{\text {OSL }}$ ) | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V} / 5 \mathrm{~V}$ |  | $\pm 2$ |  | $\mu \mathrm{A}$ |
| Supply Current (ICC) (Note 3) | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{IN}}=0 \mathrm{~V} / 5 \mathrm{~V}$ |  | 10 |  | $\mu \mathrm{A}$ |
| CMOSILPTTL INTERFACE |  |  |  |  |  |
| Logical " 1 " Input Voltage $\left(\mathrm{V}_{\operatorname{IN}(1)}\right)$ (Clock Input) | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ | 4.3 |  |  | V |
| Logical "0" Input Voltage $\left(V_{\text {IN }(0)}\right)$ (Clock Input) | $V_{C C}=5 \mathrm{~V}$ |  |  | 0.7 | V |
| Logical "1" Input Voltage ( $\mathrm{V}_{\mathrm{IN}(1)}$ ) (All Input Except Clock) | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ | 3.5 | , |  | V |
| Logical "0" Input Voltage ( $\mathrm{V}_{\mathrm{IN}(0)}$ ) (All Input Except Clock) | $V_{C C}=5 \mathrm{~V}$ |  |  | 0.4 | V |
| Logical " 1 " Output Voltage | $54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | 2.4 |  |  | V |
| (VOUT(1)) (LZO and Carry) | $74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}$ | 2.4 |  |  | V |
| Logical "0" Output Voltage | $54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ |  |  | 0.4 | V |
| ( $\mathrm{V}_{\text {OUT(0) }}$ ) (LZO and Carry) | $74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}$ |  |  | 0.4 | V |

## DC Electrical Characteristics (Continued)

| Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| OUTPUT DRIVE |  |  |  |  |  |
| Output Source Current (ISOURCE) (LZO and Carry) | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 2.6 |  | mA |
| Output Sink Current ( $I_{\text {SINK }}$ ) (LZO and Carry) | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 2.8 |  | mA |
| Output Source Current (Isource) (Segment Outputs) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 1.9 |  | mA |
| Output Sink Current (ISINK) (Segment Outputs) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 1.6 |  | mA |
| Output Source Current (I ${ }_{\text {source }}$ ) (Backplane Output) | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 16.0 |  | mA |
| Output Sink Current (I IINK) (Backplane Output) | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 13.0 |  | mA |
| Output Source Current (ISOURCE) ( $1 / 2$-Digit) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 3.8 |  | mA |
| Output Sink Current ( $I_{\text {SINK }}$ ) $(1 / 2$-Digit) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 3.2 |  | mA |

AC Electrical Characteristics $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

|  | Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd} 0}, \mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay Clock to Carry | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  |  |  |  |
| $\mathrm{f}_{\text {MAX }}$ | Maximum Clock Frequency | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  | 2 |  | MHz |
| $t_{\text {r }}, t_{\text {f }}$ | Maximum Clock Rise or Fall Time | $\mathrm{V}_{C C}=5.0 \mathrm{~V}$ |  |  | No Limit | $\mu \mathrm{S}$ |
| ${ }^{t}{ }_{\text {WR }}$ | Reset Pulse Width | $\mathrm{V}_{C C}=5.0 \mathrm{~V}$ |  |  |  | ns |
| ${ }^{\text {tws }}$ | Store Pulse Width | $\mathrm{V}_{\text {CC }}=5.0 \mathrm{~V}$ |  |  |  | ns |
| $t_{\text {SETCTK, S) }}$ | Clock to Store Set-Up Time | $\mathrm{V}_{\text {cc }}=5.0 \mathrm{~V}$ |  |  |  | ns |
| $t_{\text {SR }}$ | Store to Reset Wait Time | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  |  |  | ns |
| $t_{\text {SET }}$ | Reset to Store Set-Up Time | $\mathrm{V}_{C C}=5.0 \mathrm{~V}$ |  |  |  | ns |
| $t_{\text {SET }}$ (E, S) | Enable to Store Set-Up Time | $\mathrm{V}_{C C}=5.0 \mathrm{~V}$ |  |  |  | ns |
| $t_{\text {RR }}$ | Reset Removal | $\mathrm{V}_{\text {CC }}=5.0 \mathrm{~V}$ |  |  |  | ns |
| $t_{\text {pdc }}$ | Propagation Delay Reset to Carry | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  |  |  | ns |
| $\mathrm{f}_{\mathrm{BP}}$ | Backplane Output Frequency | Pin 36 Floating |  | 125 |  | Hz |
| $\mathrm{CIN}_{\text {IN }}$ | Input Capacitance | Logic Inputs (Note 4) |  | 5 |  | pF |
| $\mathrm{t}_{\text {ris }}$ | Segment Rise/Fall Time | $\mathrm{C}_{\text {load }}=200 \mathrm{pF}$ |  | 0.5 |  | ${ }^{\mu \mathrm{S}}$ |
| $\mathrm{t}_{\text {rfb }}$ | Backplane Rise/Fall Time | $\mathrm{C}_{\text {load }}=5000 \mathrm{pF}$ |  | 1.5 |  | $\mu \mathrm{S}$ |
| $\mathrm{f}_{\text {osc }}$ | Oscillator Frequency | Pin 36 Floating |  | 16 |  | kHz |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: These input pins have pull-ups to $V_{\text {CC }}$.
Note 3: See test circuit. Display blanked.
Note 4: Does not apply to backplane and oscillator pins.


Segment Identification


## Test Circuit

* Each segement to backplane with 200 pF capacitor.



## Block Diagram



## Control Pin Description

Backplane In/Out-When the oscillator pin is grounded this pin is an input allowing an external device to generate the backplane waveform. When the oscillator pin is left open this pin is an output supplying backplane drive for an LCD.

Oscillator-The oscillator frequency may be lowered by tying a capacitor between this pin and ground. If this pin is grounded the backplane pin becomes an input.

Store Input-This controls the latches. When low, the latches are in flow-through mode (latch outputs follow counter), but when taken high data on counter outputs is stored in latches and displayed.

Reset Input-When low, counters are reset to zero.
Clock Input-Advances counter on negative edge.
Enable Input-When low, halts counter operation.
Leading Zero Input (LZI)—When high, enables leading zero blanking.
Leading Zero Output (LZO)—This signal goes high when counter equals zero and LZ is high.

Carry Output - Goes high for one clock period when count of 9999 is reached.

A1-G1-Digit 1 segment outputs.
A2-G2-Digit 2 segment outputs.
A3-G3-Digit 3 segment outputs.
A4-G4-Digit 4 segment outputs.
½.Digit Output - Goes high when count goes from 9999 to 0000 and stays high until Reset goes low.

## Application Hints

## Counter Circuitry Description

The MM74C946 contains a 4-digit resettable synchronous counter with a Schmitt trigger on the clock input. An additional D flip-flop clocked by the counter carry out provides a true $1 / 2$-digit, or it can be used to indicate an overflow condition. The counters increment on the negative clock edge. The $1 / 2$-digit sets on the negative clock edge which increments the counter past 9999 . It can be reset only when the counter is reset by taking the reset pin to ground. The counter and carry output operation is independent of the state of the $1 / 2$-digit flip-flop.

The carry output goes high on the negative edge of the clock when the transition from 9998 to 9999 occurs and then goes low on the next count. Thus counters may be cascaded in a ripple carry mode or synchronous mode by using the enable input.

The counter can be inhibited from responding to clock input pulses by taking the enable input low, thus freezing the counter to its state prior to the event.

The counter outputs feed a series of flow-through latches. When the store input is low, the latch outputs follow their inputs. When the store input is taken high, the contents of the counter are stored in the latches and are displayed.
The latch outputs feed 4 decimal to 7 -segment decoders which include circuitry to provide leading zero blanking. When the leading zero input is low or the $1 / 2$-digit is set, leading zero blanking is inhibited. When the leading zero input is high, all leading zeroes will be blanked. A leading zero output is provided to allow correct blanking of all leading zeroes in multiple device designs. This output will be high when all 4 digits are blanked. (Remember the leading zero input must be high and the $1 / 2$-digit must be reset.)

## Display Circuitry Description

The MM74C946 has 30 segment outputs capable of directly driving 4 digits of 7 segments plus an additional $1 / 2$-digit of 2 segments. The segment and backplane drivers are designed to provide matched rise and fall times eliminating possible DC components in the driving waveforms which could degrade display life.

The backplane driver can be disabled by grounding the oscillator pin. This enables the segment output waveforms to be synchronized to an external signal applied to the backplane pin. This allows several devices to be driven by a single master backplane waveform which can be generated by another MM74C946 or an external oscillator. Thus single backplane displays with $8,12,16$, etc. digits can be driven by multiple counters. The maximum fanout of a master backplane driver is limited by its total capacitive load which is the sum of the slaved backplane input capacitances and the display backplane capacitance.
An on-board oscillator/divider generates the segment/ backplane waveforms. Its output frequency typically is 125 Hz , but may be slowed by connecting an external capacitor between the oscillator pin and ground. The oscillator pin may also be driven by an external waveform but the input low level must not go to ground or else the backplane will be put in the slave mode.


## Synchronous Cascading



[^9]
## MM74C956 4-Digit, 17-Segment Alpha-Numeric Display Driver, with Memory, Decoder, and LED Drivers

## General Description

The MM74C956 monolithic LED intelligent display driver circuit is manufactured using standard complementary MOS technology. The convention and speed of the data entry procedure is designed to be microprocessor bus and TTL compatible with no interface circuitry required.
The integrated circuit has memory to store four 7-bit ASCII words corresponding to the four digits, an ASCII to 17 -segment alpha-numeric ROM decoder, multiplexing and drive circuitry to drive four 17 -segment digits. It has direct drive capabilities of $2.5 \mathrm{~mA} /$ segment average current.
The internal memory can be written asynchronously through the 7 -bit data bus (D0-D6) into the digit location addressed by the 2-bit address bus (AO, A1). For multiple chip circuits, two chip select inputs ( $\overline{\mathrm{CE}}, \overline{\mathrm{CE} 2}$ ) can be decoded or a one-of-n decoder can be used for displays incorporating more than four MM74C956's.
The cursor function will cause all segments of a digit to be lit but will not write over the contents of the memory corresponding to that digit. Therefore, when the cursor is erased, the original character will reappear at that digit location.

## Features

- Microprocessor bus compatible
- All inputs are TTL compatible; 5 V power supply
- On-chip memory
- On-chip decoder converts from standard 7-bit ASCII to alpha-numeric
- On-chip multiplexing with LED segment and digit drivers
- Independent and asynchronous digit access
- Independent cursor function: can be disabled
- Display clear function
- Display blank function
- Two chip select inputs for multiple chip systems


## Block Diagram



Connection Diagram
Dual-In-Line Package


## Absolute Maximum Ratings (Note 1)

Voltage at Any Pin
Operating Temperature Range MM74C956
Storage Temperature Range
-0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$

Package Dissipation
700 mW Operating $\mathrm{V}_{\mathrm{CC}}$ Range 4.5 V to 5.5 V $V_{C C}$ 6.0 V $300^{\circ} \mathrm{C}$

DC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}$

| Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {IN(1) }}$ Logical "1" Input Voltage | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ | 2.4 |  |  | v |
| $\mathrm{V}_{\text {IN(0) }}$ Logical "0" Input Voltage | $\mathrm{V}_{\text {CC }}=5.0 \mathrm{~V}$ |  |  | 0.8 | v |
| $\mathrm{I}_{1 \times(1)}$ Logical "1" Input Current | $\mathrm{V}_{\text {CC }}=5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=5 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {IN(0) }}$ Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -100.0 | 25.0 |  | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {CC }}$ Supply Current | $V_{C C}=5 V$ (i1) $T_{A}=25^{\circ} \mathrm{C}$ <br> All Outputs Open <br> All Inputs (a) 5 V |  | 0.5 | 1.0 | mA |
| OUTPUT DRIVE (Notes 2 and 3) |  |  |  |  |  |
| Peak Output Source Current (ISOURCE) (P-Channel Segment Driver with 1 Segment On) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.9 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ |  |  | 14.8 | mA |
| Peak Output Source Current (Isource) (P-Channel Segment Driver with 17 Segments On) | $\begin{aligned} & V_{C C}=16 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=3.3 \mathrm{~V} \\ & T_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 4.2 |  |  | mA |
| Peak Output Sink Current (I ${ }_{\text {SINK }}$ ) (N-Channel Digit Driver with 3 Segments On) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} . \mathrm{V}_{\text {OUT }}=0.25 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | 18.5 |  |  | mA |
| Peak Output Sink Current (ISINK) <br> (N-Channel Digit Driver with 17 Segments On) | $\begin{aligned} & V_{C C}=16 \mathrm{~V} \mathrm{~V}_{\text {OUT }}=1.3 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ |  |  | 172.0 | mA |

## AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$

| Symbol | Parameter | Conditions | Min | Typ | Max |
| :---: | :--- | :--- | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{w}}$ | Write Pulse Width | All Inputs Swing from OV-4V | 240 |  |  |
| $\mathrm{t}_{\mathrm{DS}}$ | Data Set-Up Time | All Inputs Swing from OV-4V | 100 |  | ns |
| $\mathrm{t}_{\mathrm{DH}}$ | Data Hold Time | All Inputs Swing from OV-4V | 50 |  | ns |
| $\mathrm{t}_{\mathrm{AS}}$ | Address Set-Up Time | All Inputs Swing from 0V-4V | 300 |  | ns |
| $\mathrm{t}_{\text {AH }}$ | Address Hold Time | All Inputs Swing from 0V-4V | 0 |  | ns |
| $\mathrm{t}_{\mathrm{CLR}}$ | Clear Time | -All Inputs Swing from OV-4V | 1 |  | ns |

Note 1: Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. Except for Operating Range they are not meant to imply that the devices should be operated at these limits. The table of Electrical Characteristics provides conditions for actual device operation.
Note 2: Average drive current $\approx$ peak drive current $\div 4$.
Note 3: Current/segment is dependent upon total number of segments on. Maximum current occurs with 1 segment on; minimum current occurs with 17 segments on.

Timing Diagram for data access


## Functional Description

## Entry into Data Memory

To enter an ASCII code，the $\overline{\mathrm{CE} 1}$ and $\overline{\mathrm{CE} 2}$ inputs must be low，$\overline{\mathrm{CU}}$ must be high．When the address is set up at AO and A1，the WE can go low，at which time the internal RAM will respond to the data inputs（D0－D6）．Note that the data need not be set up prior to the $\overline{W E}$ transition．
All digits can be cleared by holding the $\overline{C L R}$ input low for the specified interval．

## Entry into Cursor Memory

This is accomplished by setting the $\overline{\mathrm{CE} 1}$ and $\overline{\mathrm{CE} 2}$ inputs as well as the $\overline{C U}$ input low．The cursor memory consists of 4 bits corresponding to the four digits，each one ad－ dressable by way of the AO and A1 inputs．Once the address is stable，the $\overline{W E}$ input must go low and the cursor memory will respond to the DO input．That is，if DO is high，a cursor will be written and if $D 0$ is low，the cursor will be erased．$\overline{C L R}$ will not erase a cursor．A cursor will only be displayed when CUE is high and the cursor function can be bypassed by tying CUE low．A flashing cursor can be implemented by pulsing CUE；this results in alternately displaying the cursor and the character originally written in that digit．CUE will not alter the contents of either the cursor or data memory．

## Blanking the Display

Display blanking can be realized by using the $\overline{B L}$ input．By taking BL low，the display will be disabled while leaving the contents of the data and cursor memory unchanged．A flashing display will occur if $\overline{B L}$ is pulsed．The display is blanked by $\overline{B L}$ regardless of whether a cursor or charac－ ter is being displayed．

## Illegal Code

If an illegal ASCII code is entered into the data memory （i．e．， $\mathrm{D} 6=\mathrm{D} 5$ ）the display will automatically be blanked for the corresponding digit．

## OSD Pin

Taking the OSD pin high disables the internal oscillator and prohibits normal multiplex scanning．This pin is pulled low internally and is primarily meant to be used in testing the part only．This pin should be grounded or left open in normal operation．

## Clearing the Display

Pulsing the $\overline{C L R}$ pin low for the specified time will clear all internal data memories while leaving the cursor memories unchanged．

TABLE I．DATA AND CURSOR ENTRY FUNCTION EXAMPLE
Assume initially $\mathrm{D} 6=1$ and $\mathrm{D} 5-\mathrm{D} 0=0$ for all internal digit memories．Cursor memory is cleared．Table is intended to be read in sequence．

|  | BL CE1 | CE2 |  |  |  | CLR | A1 AO | D6 | D5 | D4 | D3 | D2 | D1 | D0 | $\begin{gathered} \text { DIG } \\ 3 \end{gathered}$ | $\begin{gathered} \text { DIG } \\ 2 \end{gathered}$ | $\begin{gathered} \text { DIG } \\ 1 \end{gathered}$ | $\begin{gathered} \text { DIG } \\ 0 \end{gathered}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | 0 X | X | X | $X$ | $x$ | 1 | $\mathrm{X} \times$ | X | $X$ | $X$ | X | X | X | X |  |  |  |  |
|  | 11 | 0 | X | X | X | 1 | $\mathrm{X} \times$ | $X$ | X | X | $X$ | X | $X$ | X | E1 | E－I | －10 | －－1 |
|  | 10 | 1 | X | $X$ | X | 1 | $\mathrm{X} \times$ | $X$ | $X$ | $X$ | $X$ | $X$ | $X$ | X | E1 | －1 | －1 | －1 |
|  | 10 | 0 | $x$ | X | 1 | 1 | $\times \mathrm{X}$ | X | $X$ | X | X | X | X | X | E－1 | －1 | －1 | －1 |
|  | 10 | 0 | $x$ | 1 | 0 | 1 | 00 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | －1 | －1 | －1， | － |
|  | 10 | 0 | X | 1 | 0 | 1 | 10 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | －1 | 1 | －1 | I－7 |
|  | $\times \quad \times$ | $X$ | $x$ | $X$ | X | 0 | $\times \times$ | X | X | X | X | X | $X$ | X |  |  |  |  |
|  | 10 | 0 | $x$ | 1 | 0 | 1 | 00 | 1 | 0 | 0 | 0 | 0 | 0 | 1 |  |  |  | F－1 |
|  | 10 | 0 | $x$ | 1 | 0 | 1 | 01 | 1 | 0 | 0 | 0 | 0 | 1 | 0 |  |  | －I | 5 |
|  | 10 | 0 | X | 1 | 0 | 1 | 10 | 1 | 0 | 0 | 0 | 0 | 1 | 1 |  | ${ }_{1}^{-}$ | －11 | F－1 |
|  | 10 | 0 | X | 1 | 0 | 1 | 11 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | －11 | －－ | －18 | 5 |
|  | 10 | 0 | 1 | 0 | 0 | 1 | 00 | $x$ | X | $x$ | $X$ | X | X | 1 | $\xrightarrow{-1}$ | ${ }_{1-}^{1-}$ | －1 | 圱 |
|  | 10 | 0 | 1 | 0 | 0 | 1 | 01 | X | X | $x$ | $X$ | X | X | 1 | －11 | 1－－ | 圱 | 或 |
|  | 10 | 0 | 1 | 0 | 0 | 1 | 11 | $X$ | X | $X$ | $X$ | X | X | 1 | 些 | － | 或 | 式 |
|  | 10 | 0 | 1 | 0 | 0 | 1 | 10 | $X$ | $X$ | $x$ | $X$ | X | X | 1 | 気 | 言 | 気 | 言 |
|  | 1 X | $x$ | 0 | 1 | 1 | 1 | $\mathrm{X} \times$ | $x$ | $X$ | $X$ | $X$ | X | X | X | $\cdots$ | － | －1 | F－1 |
|  | 1 X | $X$ | 1 | 1 | 1 | 1 | X X | $X$ | X | $X$ | $X$ | $X$ | X | X | 会年 | 可 | 少 | 会 |
|  | 10 | 0 | 1 | 0 | 0 | 1 | 00 | X | X | X | X | X | X | 0 | 言 | 第 | 可 | F－1 |
|  | 1 0 |  |  |  | 0 | 1 | 0 | $x$ | X | X | X | X | X | 0 | 枒 | 通 | 國 | 5 |
|  | 10 | 0 | 0 | 0 | 0 | 1 | 10 | X | X | X | X | $X$ | X | 0 | －11 | ${ }_{1}^{-}$ | －11 | F－1 |
|  | 1 X | $x$ | 1 | 1 | 1 | 1 | $\times \mathrm{x}$ | X | X | $x$ | $x$ | X | X | X | 等 | － | 圱 | F－1 |
|  | $0 \cdot x$ | $x$ | X | 1 | 1 | 1 | $x \times$ | X | X | X | X | $X$ | X | X |  | －－ |  |  |
|  | 1 X | $x$ | 1 | 1 | 1 | 1 | X X | X | X | X | $x$ | $X$ | X | $X$ | 圱 | $\begin{aligned} & -- \\ & 1-2 \end{aligned}$ | 答 | F－1 |
|  | 1 X | $x$ | 1 | 1 | X | 0 | $\times \times$ | $x$ | $x$ | X | X | $x$ | X | $x$ | 亚 |  | 答 |  |
|  | 10 | 0 | 1 | 0 | 0 | 1 | 11 | $x$ | $x$ | X | $x$ |  | $x$ | 0 |  |  | 圱 |  |
|  | 10 | 0 | 1 | 0 | 0 | 1 |  |  | X | X | X |  |  | 0 |  |  |  |  |
| $\mathrm{X}=$ don＇t care |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |

TABLE II．ROM OUTPUT FONT FOR ASCII TO ALPHA－NUMERIC DECODING

| Character Set |  |  |  |  | L | H | L | H | L | H | L | H |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | L | L | H | H | L | L | H | H |
|  |  |  |  |  | L | L | L | L | H | H | H | H |
| L | H | L | L |  |  | $!$ | 11 | －1．1 | II | K K | $\begin{aligned} & \bar{I} \\ & I \geq y \end{aligned}$ | 7 |
| L | H | L | H |  | 1 | 1 | 少 | －1 | ／ | －－ | － | ，＇ |
| L | H | H | L |  | II | 1 | I－ | －1 | 111 | I－ | İ | 7 |
| L | H | H | H |  | İ | $\underline{1}$ |  | ／ | － | －－ | －1 | 1 |
| H | L | L | L |  | E－I | $1-1$ | $\begin{array}{r} 71 \\ -1 \end{array}$ | $\begin{aligned} & -- \\ & 1-2 \\ & 1 \end{aligned}$ | $\begin{aligned} & 71 \\ & 11 \end{aligned}$ | E- | $\mathrm{I}^{-}$ |  |
| H | L | L | H |  | 1－1 | －1 | $\begin{aligned} & 7 \\ & 1 \\ & 1 \end{aligned}$ | IT | I＿－ | $\begin{array}{ll} \hline N 1 \\ 1 \end{array}$ | ハ 1 | $\begin{aligned} & -1 \\ & 1-1 \end{aligned}$ |
| H | L | H | L |  | I－I | $\begin{aligned} & 1-1 \\ & 1-y \end{aligned}$ | $5$ | I－－ | $7$ | $\begin{array}{\|lll} 1 & 1 \\ 1 & 1 \end{array}$ | $11$ | $\begin{array}{ll} 1 & 1 \\ 1 & 1 \end{array}$ |
| H | L | H | H |  | ハ | $1 /$ | $\begin{aligned} & -7 \\ & 1 \end{aligned}$ | $\begin{aligned} & 1 \\ & 1 \end{aligned}$ | $\backslash$ | -1 | 八 | －－ |

Typical Application


## Section 3

CMOS A/D Converters

## ADC0808, ADC0809 8-Bit $\mu$ P Compatible A/D Converters With 8-Channel Multiplexer

## General Description

The ADC0808, ADC0809 data acquisition component is a monolithic CMOS device with an 8 -bit analog-to-digital converter, 8-channel multiplexer and microprocessor compatible control logic. The 8-bit A/D converter uses successive approximation as the conversion technique. The converter features a high impedance chopper stabilized comparator, a 256R voltage divider with analog switch tree and a successive approximation register. The 8 -channel multiplexer can directly access any of 8 -single-ended analog signals.
The device eliminates the need for external zero and fullscale adjustments. Easy interfacing to microprocessors is provided by the latched and decoded multiplexer address inputs and latched TTL TRI-STATE® outputs.

The design of the ADC0808, ADC0809 has been optimized by incorporating the most desirable aspects of several A/D conversion techniques. The ADC0808, ADC0809 offers high speed, high accuracy, minimal temperature dependence, excellent long-term accuracy and repeatability, and consumes minimal power. These features make this device ideally suited to applications from process and machine control to consumer and automotive applications. For 16 -channel multiplexer with common output (sample/hold port) see ADC0816 data sheet. (See AN-247 for more information.

## Features

- Resolution - 8-bits
- Total unadjusted error $- \pm 1 / 2$ LSB and $\pm 1$ LSB
- No missing codes
- Conversion time - $100 \mu \mathrm{~s}$
- Single supply $-5 V_{D C}$
- Operates ratiometrically or with $5 \mathrm{~V}_{\mathrm{DC}}$ or analog span adjusted voltage reference
- 8-channel multiplexer with latched control logic
- Easy interface to all microprocessors, or operates "stand alone"
- Outputs meet $T^{2} L$ voltage level specifications
- 0 V to 5 V analog input voltage range with single 5 V supply
- No zero or full-scale adjust required
- Standard hermetic or molded 28 -pin DIP package
- Temperature range $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ or $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
- Low power consumption - 15 mW
- Latched TRI-STATE ${ }^{\circledR}$ output


[^10]
# Absolute Maximum Ratings (Notes 1 and 2) 

Operating Ratings (Notes 1 and 2 )
Supply Voltage $\left(\mathrm{V}_{\mathrm{CC}}\right)($ Note 3$) \quad 6.5 \mathrm{~V}$
Voltage at Any Pin $\quad-0.3 \mathrm{~V}$ to $\left(\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}\right)$
Except Control Inputs
Voltage at Control Inputs
-0.3 V to +15 V
(START, OE, CLOCK, ALE, ADD A, ADD B, ADD C)
Storage Temperature Range
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
Package Dissipation at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
875 mW
Lead Temperature (Soldering, 10 seconds)
$-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$
4.5 $\mathrm{V}_{\mathrm{DC}}$ to $6.0 \mathrm{~V}_{\mathrm{DC}}$

## Electrical Characteristics

Conyerter Specifications: $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}_{\mathrm{DC}}=\mathrm{V}_{\mathrm{REF}(+)}, \mathrm{V}_{\mathrm{REF}(-)}=\mathrm{GND}, \mathrm{T}_{\mathrm{MIN}} \leq \mathrm{T}_{\mathrm{A}} \leq \mathrm{T}_{\mathrm{MAX}}$ and $\mathrm{f}_{\mathrm{CLK}}=640 \mathrm{kHz}$ unless otherwise stated.

|  | Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\begin{aligned} & V_{\operatorname{REF}(+)} \\ & \frac{V_{\operatorname{REF}(+)}+\mathrm{V}_{\mathrm{REF}(-)}}{2} \end{aligned}$ | ADC0808 <br> Total Unadjusted Error (Note 5) | $25^{\circ} \mathrm{C}$ <br> $\mathrm{T}_{\text {MIN }}$ to $\mathrm{T}_{\text {MAX }}$ <br> $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ <br> $\mathrm{T}_{\text {MIN }}$ to $\mathrm{T}_{\text {MAX }}$ <br> From Ref( + ) to Ref( - ) <br> (Note 4) $\mathrm{V}(+$ ) or $\mathrm{V}(-)$ <br> Measured at $\operatorname{Ref}(+$ ) | $\begin{gathered} 1.0 \\ \text { GND-0.10 } \end{gathered}$ | 2.5 | $\pm 1 / 2$ $\pm 3 / 4$ | $\begin{aligned} & \text { LSB } \\ & \text { LSB } \end{aligned}$ |
|  | ADC0809 |  |  |  |  |  |
|  | Total Unadjusted Error (Note 5) |  |  |  | $\begin{aligned} & \pm 1 \\ & \pm 1 \quad 1 / 4 \end{aligned}$ | $\begin{aligned} & \text { LSB } \\ & \text { LSB } \end{aligned}$ |
|  | Input Resistance |  |  |  |  | k $\Omega$ |
|  | Analog Input Voltage Range |  |  |  | $\mathrm{V}_{\mathrm{CC}}+0.10$ | $V_{D C}$ |
|  | Voltage, Top of Ladder |  |  | $\mathrm{V}_{\mathrm{cc}}$ | $\mathrm{V}_{\mathrm{CC}}+0.1$ | V |
|  | Voltage, Center of Ladder |  | $V_{C C} / 2-0.1$ | $\mathrm{V}_{\mathrm{CC}} / 2$ | $\mathrm{V}_{\mathrm{cc}} / 2+0.1$ | V |
| $\mathrm{V}_{\text {REF( }- \text { ) }}$ | Voltage, Bottom of Ladder | Measured at $\operatorname{Ref}(-)$ | -0.1 | 0 |  | V |
|  | Comparator Input Current | $\mathrm{f}_{\mathrm{c}}=640 \mathrm{kHz}$, (Note 6) | -2 | $\pm 0.5$ | 2 | $\mu \mathrm{A}$ |

## Electrical Characteristics

Digital Levels and DC Specifications: ADC0808CJ $4.5 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CC}} \leq 5.5 \mathrm{~V},-55^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+125^{\circ} \mathrm{C}$ unless otherwise noted ADC0808CCJ, ADC0808CCN, and ADC0809CCN $4.75 \leq \mathrm{V}_{\mathrm{CC}} \leq 5.25 \mathrm{~V},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ unless otherwise noted


## Electrical Characteristics (Continued)

Digital Levels and DC Specifications: ADC0808CJ $4.5 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CC}} \leq 5.5 \mathrm{~V},-55^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+125^{\circ} \mathrm{C}$ unless otherwise noted ADC0808CCJ, ADC0808CCN, and ADC0809CCN $4.75 \leq \mathrm{V}_{\mathrm{CC}} \leq 5.25 \mathrm{~V},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ unless otherwise noted


## Electrical Characteristics

Timing Specifications: $\mathrm{V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{REF}(+)}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{REF}(-)}=\mathrm{GND}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$ and $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted.

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {ws }}$ | Minimum Start Pulse Width | (Figure 5) |  | 100 | 200 | ns |
| $t_{\text {WALE }}$ | Minimum ALE Pulse Width | (Figure 5) |  | 100 | 200 | ns |
| $t_{\text {s }}$ | Minimum Address Set-Up Time | (Figure 5) |  | 25 | 50 | ns |
| $t_{H}$ | Minimum Address Hold Time | (Figure 5) |  | 25 | 50 | ns |
| $t_{D}$ | Analog MUX Delay Time From ALE | $\mathrm{R}_{\mathrm{S}}=0 \Omega$ (Figure 5) |  | 1 | 2.5 | $\mu \mathrm{S}$ |
| $\mathrm{t}_{\mathrm{H} 1}, \mathrm{t}_{\mathrm{HO}}$ | OE Control to Q Logic State | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}$ (Figure 8) |  | 125 | 250 | ns |
| $t_{1 H}, t_{\text {OH }}$ | OE Control to $\mathrm{Hi}-\mathrm{Z}$ | $\mathrm{C}_{\mathrm{L}}=10 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}$ (Figure 8) |  | 125 | 250 | ns |
| $t_{c}$ | Conversion Time | $\mathrm{f}_{\mathrm{c}}=640 \mathrm{kHz}$, (Figure 5) ( ( lote 7) | 90 | 100 | 116 | $\mu \mathrm{S}$ |
| $\mathrm{f}_{\mathrm{c}}$ | Clock Frequency |  | 10 | 640 | 1280 | kHz |
| $\mathrm{t}_{\mathrm{EOC}}$ | EOC Delay Time | (Figure 5) | 0 |  | $8+2 \mu \mathrm{~s}$ | Clock <br> Periods |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | At Control Inputs |  | 10 | 15 | pF |
| $\mathrm{C}_{\text {OUT }}$ | TRI-STATE ${ }^{\oplus}$ Output Capacitance | At TRI-STATE® Outputs, (Note 12) |  | 10 | 15 | pF |

Note 1: Absolute maximum ratings are those values beyond which the life of the device may be impaired.
Note 2: All voltages are measured with respect to GND, unless otherwise specified.
Note 3: A zener diode exists, internally, from $V_{C C}$ to $G N D$ and has a typical breakdown voltage of $7 \mathrm{~V}_{\mathrm{DC}}$ -
Note 4: Two on-chip diodes are tied to each analog input which will forward conduct for analog input voltages one diode drop below ground or one diode drop greater than the $V_{C C}$ supply. The spec allows 100 mV forward bias of either diode. This means that as long as the analog $V_{\text {IN }}$ does not exceed the supply voltage by more than 100 mV , the output code will be correct. To achieve an absolute $0 \mathrm{~V}_{\mathrm{DC}}$ to $5 \mathrm{~V}_{\mathrm{DC}}$ input voltage range will therefore require a minimum supply voltage of $4.900 \mathrm{~V}_{\mathrm{DC}}$ over temperature variations, initial tolerance and loading.
Note 5: Total unadjusted error includes offset, full-scale, linearity, and multiplexer errors. See Figure 3. None of these A/Ds requires a zero or full-scale adjust. However, if an all zero code is desired for an analog input other than 0.0 V , or if a narrow full-scale span exists (for example: 0.5 V to 4.5 V full-scale) the reference voltages can be adjusted to achieve this. See Figure 13.
Note 6: Comparator input current is a bias current into or out of the chopper stabilized comparator. The bias current varies directly with clock frequency and has little temperature dependence (Figure 6). See paragraph 4.0.
Note 7: The outputs of the data register are updated one clock cycle before the rising edge of EOC.

## Functional Description

Multiplexer: The device contains an 8-channel singleended analog signal multiplexer. A particular input channel is selected by using the address decoder. Table I shows the input states for the address lines to select any channel. The address is latched into the decoder on the low-to-high transition of the address latch enable signal.

TABLE I

| SELECTED | ADDRESS LINE |  |  |
| :---: | :---: | :---: | :---: |
| ANALOG CHANNEL | C | B | A |
| IN0 | L | L | L |
| IN1 | L | L | H |
| IN2 | L | H | L |
| IN3 | L | H | H |
| IN4 | H | L | L |
| IN5 | H | L | H |
| IN6 | H | H | L |
| IN7 | H | H | H |

## CONVERTER CHARACTERISTICS

## The Converter

The heart of this single chip data acquisition system is its 8 -bit analog-to-digital converter. The converter is designed
to give fast, accurate, and repeatable conversions over a wide range of temperatures. The converter is partitioned into 3 major sections: the 256R ladder network, the successive approximation register, and the comparator. The converter's digital outputs are positive true.

The 256R ladder network approach (Figure 1) was chosen over the conventional R/2R ladder because of its inherent monotonicity, which guarantees no missing digital codes. Monotonicity is particularly important in closed loop feedback control systems. A non-monotonic relationship can cause oscillations that will be catastrophic for the system. Additionally, the 256R network does not cause load variations on the reference voltage.

The bottom resistor and the top resistor of the ladder network in Figure 1 are not the same value as the remainder of the network. The difference in these resistors causes the output characteristic to be symmetrical with the zero and full-scale points of the transfer curve. The first output transition occurs when the analog signal has reached $+1 / 2$ LSB and succeeding output transitions occur every 1 LSB later up to full-scale.

The successive approximation register (SAR) performs 8 iterations to approximate the input voltage. For any SAR type converter, $n$-iterations are required for an $n$-bit converter. Figure 2 shows a typical example of a 3-bit converter. In the ADC0808, ADC0809, the approximation technique is extended to 8 bits using the 256R network.


FIGURE 1. Resistor Ladder and Switch Tree

## Functional Description (Continued)

The A/D converter's successive approximation register (SAR) is reset on the positive edge of the start conversion (SC) pulse. The conversion is begun on the falling edge of the start conversion pulse. A conversion in process will be interrupted by receipt of a new start conversion pulse. Continuous conversion may be accomplished by tying the end-of-conversion (EOC) output to the SC input. If used in this mode, an external start conversion pulse should be applied after power up. End-of-conversion will go low between 0 and 8 clock pulses after the rising edge of start conversion.

The most important section of the A/D converter is the comparator. It is this section which is responsible for the ultimate accuracy of the entire converter. It is also the

FIGURE 2. 3-Bit A/D Transfer Curve

comparator drift which has the greatest influence on the repeatability of the device. A chopper-stabilized comparator provides the most effective method of satisfying all the converter requirements.

The chopper-stabilized comparator converts the DC input signal into an AC signal. This signal is then fed through a high gain AC amplifier and has the DC level restored. This technique limits the drift component of the amplifier since the drift is a DC component which is not passed by the AC amplifier. This makes the entire AID converter extremely insensitive to temperature, long term drift and input offset errors.
Figure 4 shows a typical error curve for the ADC0808 as measured using the procedures outlined in AN-179.


FIGURE 3. 3-Bit AID Absolute Accuracy Curve


FIGURE 4. Typical Error Curve

Connection Diagram

## Dual-In-Line Package



Timing Diagram


FIGURE 5

## Typical Performance Characteristics



FIGURE 6. Comparator $\mathrm{I}_{\mathrm{IN}}$ vs $\mathrm{V}_{\mathrm{IN}}$ $\left(\mathrm{V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{REF}}=5 \mathrm{~V}\right)$


FIGURE 7. Multiplexer $\mathrm{R}_{\mathbf{O N}}$ vs $\mathrm{V}_{\text {IN }}$ $\left(\mathrm{V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{REF}}=5 \mathrm{~V}\right)$

## TRI-STATE ${ }^{\circledR}$ Test Circuits and Timing Diagrams



$$
t_{0 H}, C_{L}=10 \mathrm{pF}
$$




FIGURE 8

## Applications Information

## OPERATION

### 1.0 Ratiometric Conversion

The ADC0808, ADC0809 is designed as a complete Data Acquisition System (DAS) for ratiometric conversion systems. In ratiometric systems, the physical variable being measured is expressed as a percentage of full-scale which is not necessarily related to an absolute standard. The voltage input to the ADC0808 is expressed by the equation

$$
\begin{equation*}
\frac{v_{I N}}{v_{\mathrm{fs}}-v_{Z}}=\frac{D_{X}}{D_{\text {MAX }}-D_{\text {MIN }}} \tag{1}
\end{equation*}
$$

$V_{\text {IN }}=$ Input voltage into the ADC0808
$\mathrm{V}_{\text {fs }}=$ Full-scale voltage
$V_{Z}=$ Zero voltage
$D_{X}=$ Data point being measured
$\mathrm{D}_{\text {MAX }}=$ Maximum data limit
$D_{\text {MIN }}=$ Minimum data limit
A good example of a ratiometric transducer is a potentiometer used as a position sensor. The position of the wiper is directly proportional to the output voltage which is a ratio of the full-scale voltage across it. Since the data is represented as a proportion of full-scale, reference requirements are greatly reduced, eliminating a large source of error and cost for many applications. A major advantage of the ADC0808, ADC0809 is that the input voltage range is equal to the supply range so the transducers can be connected directly across the supply and their outputs connected directly into the multiplexer inputs, (Figure 9).

Ratiometric transducers such as potentiometers, strain gauges, thermistor bridges, pressure transducers, etc., are suitable for measuring proportional relationships; however, many types of measurements must be referred to an absolute standard such as voltage or current. This means a system reference must be used which relates the full-scale voltage to the standard volt. For example, if $V_{C C}=V_{\text {REF }}=5.12 \mathrm{~V}$, then the full-scale range is divided into 256 standard steps. The smallest standard step is 1 LSB which is then 20 mV .

### 2.0 Resistor Ladder Limitations

The voltages from the resistor ladder are compared to the selected input 8 times in a conversion. These voltages are coupled to the comparator via an analog switch tree which is referenced to the supply. The voltages at the top, center and bottom of the ladder must be controlled to maintain proper operation.

The top of the ladder, $\operatorname{Ref}(+$ ), should not be more positive than the supply, and the bottom of the ladder, Ref( - ), should not be more negative than ground. The center of the ladder voltage must also be near the center of the supply because the analog switch tree changes from N -channel switches to P-channel switches. These limitations are automatically satisfied in ratiometric systems and can be easily met in ground referenced systems.

Figure 10 shows a ground referenced system with a separate supply and reference. In this system, the supply must be trimmed to match the reference voltage. For instance, if a 5.12 V is used, the supply should be adjusted to the same voltage within 0.1 V .


FIGURE 9. Ratiometric Conversion System

## Applications Information (Continued)

The ADC0808 needs less than a milliamp of supply current so developing the supply from the reference is readily accomplished. In Figure 11 a ground referenced system is shown which generates the supply from the reference. The buffer shown can be an op amp of sufficient drive to supply the milliamp of supply current and the desired bus drive, or if a capacitive bus is driven by the outputs a large capacitor will supply the transient supply current as seen in Figure 12. The LM301 is overcompensated to insure stability when loaded by the $10 \mu \mathrm{~F}$ output capacitor.

The top and bottom ladder voltages cannot exceed $\mathrm{V}_{\mathrm{CC}}$ and ground, respectively, but they can be symmetrically less than $\mathrm{V}_{\mathrm{CC}}$ and greater than ground. The center of the ladder voltage should always be near the center of the supply. The sensitivity of the converter can be increased, (i.e., size of the LSB steps decreased) by using a symmetrical reference system. In Figure 13, a 2.5 V reference is symmetrically centered about $\mathrm{V}_{\mathrm{Cd}} / 2$ since the same current flows in identical resistors. This system with a 2.5 V reference allows the LSB bit to be half the size of a 5 V reference system.


FIGURE 10. Ground Referenced Conversion System Using Trimmed Supply


FIGURE 11. Ground Referenced Conversion System with Reference Generating $\mathbf{V}_{\mathbf{C C}}$ Supply

## Applications Information (Continued) $\quad 10-15 \mathrm{~V}_{\mathrm{DC}}$



FIGURE 12. Typical Reference and Supply Circuit


FIGURE 13. Symmetrically Centered Reference

### 3.0 Converter Equations

The transition between adjacent codes N and $\mathrm{N}+1$ is given by:

$$
\begin{equation*}
V_{I N}=\left\{\left(V_{R E F(+)}-V_{\operatorname{REF}(-)}\right)\left[\frac{N}{256}+\frac{1}{512}\right] \pm V_{\operatorname{TUE}}\right\}+V_{R E F(-)} \tag{2}
\end{equation*}
$$

The center of an output code N is given by:

$$
\begin{equation*}
V_{I N}=\left\{\left(V_{R E F(+)}-V_{\operatorname{REF}(-)}\right)\left[\frac{N}{256}\right] \pm V_{\operatorname{TUE}}\right\}+V_{\operatorname{REF}(-)} \tag{3}
\end{equation*}
$$

The output code N for an arbitrary input are the integers within the range:

$$
\begin{equation*}
N=\frac{V_{I N}-V_{\operatorname{REF}(-)}}{V_{\operatorname{REF}(+)}-V_{\operatorname{REF}(-)}} \times 256 \pm \text { Absolute Accuracy } \tag{4}
\end{equation*}
$$

where: $\mathrm{V}_{\mathbb{I N}}=$ Voltage at comparator input
$\mathrm{V}_{\mathrm{REF}(+)}=$ Voltage at $\operatorname{Ref}(+)$
$\mathrm{V}_{\mathrm{REF}(-)}=$ Voltage at Ref(-)
$\mathrm{V}_{\text {TUE }}=$ Total unadjusted error voltage (typically $\left.\mathrm{V}_{\mathrm{REF}(+)} \div 512\right)$

### 4.0 Analog Comparator Inputs

The dynamic comparator input current is caused by the periodic switching of on-chip stray capacitances. These are connected alternately to the output of the resistor ladder/switch tree network and to the comparator input as part of the operation of the chopper stabilized comparator.

The average value of the comparator input current varies directly with clock frequency and with $\mathrm{V}_{\mathrm{IN}}$ as shown in Figure 6.

If no filter capacitors are used at the analog inputs and the signal source impedances are low, the comparator input current should not introduce converter errors, as the transient created by the capacitance discharge will die out before the comparator output is strobed.

If input filter capacitors are desired for noise reduction and signal conditioning they will tend to average out the dynamic comparator input current. It will then take on the characteristics of a DC bias current whose effect can be predicted conventionally.

## Typical Application



* Address latches needed for 8085 and SC/MP interfacing the ADC0808 to a microprocessor

MICROPROCESSOR INTERFACE TABLE

| PROCESSOR | $\overline{\text { READ }}$ | $\overline{\text { WRITE }}$ | INTERRUPT (COMMENT) |
| :--- | :--- | :--- | :--- |
| 8080 | $\overline{\text { MEMR }}$ | $\overline{\text { MEMW }}$ | INTR (Thru RST Circuit) |
| 8085 | $\overline{\text { RD }}$ | $\overline{\text { WR }}$ | INTR (Thru RST Circuit) |
| Z-80 | $\overline{\text { RD }}$ | $\overline{\text { WR }}$ | $\overline{\text { INT (Thru RST Circuit, Mode 0) }}$ |
| SCIMP | NRDS | NWDS | SA (Thru Sense A) |
| 6800 | VMA• $\phi 2 \cdot R / W$. | VMA• $\phi 2 \cdot \overline{R / W}$ | $\overline{\text { IRQA or IRQB } \text { (Thru PIA) }}$ |

## ADC0816, ADC0817 8-Bit $\mu$ P Compatible AID Converters with 16-Channel Multiplexer

## General Description

The ADC0816, ADC0817 data acquisition component is a monolithic CMOS device with an 8-bit analog-to-digital converter, 16 -channel multiplexer and microprocessor compatible control logic. The 8 -bit A/D converter uses successive approximation as the conversion technique. The converter features a high impedance chopper stabilized comparator, a 256R voltage divider with analog switch tree and a successive approximation register. The 16 -channel multiplexer can directly access any one of 16 -singleended analog signals, and provides the logic for additional channel expansion. Signal conditioning of any analog input signal is eased by direct access to the multiplexer output, and to the input of the 8 -bit A/D converter.

The device eliminates the need for external zero and fullscale adjustments. Easy interfacing to microprocessors is provided by the latched and decoded multiplexer address inputs and latched TTL TRI-STATE ${ }^{\circledR}$ outputs.
The design of the ADC0816, ADC0817 has been optimized by incorporating the most desirable aspects of several AID conversion techniques. The ADC0816, ADC0817 offers high speed, high accuracy, minimal temperature dependence, excellent long-term accuracy and repeatability, and consumes minimal power. These features make this device ideally suited to applications from process and machine control to consumer and automotive applications. For similar performance in an 8-channel, 28 -pin,

8 -bit A/D converter, see the ADC0808, ADC0809 data sheet. (See AN-258 for more information.)

## Features

- Resolution - 8-bits
- Total unadjusted error $- \pm 1 / 2$ LSB and $\pm 1$ LSB
- No missing codes
- Conversion time - $100 \mu \mathrm{~s}$
- Single supply - $5 \mathrm{~V}_{\mathrm{DC}}$
- Operates ratiometrically or with $5 \mathrm{~V}_{\mathrm{DC}}$ or analog span adjusted voltage reference.
- 16-channel multiplexer with latched control logic
- Easy interface to all microprocessors, or operates "stand alone"
- Outputs meet $T^{2} L$ voltage level specifications
- 0 V to 5 V analog input voltage range with single 5 V supply
- No zero or full-scale adjust required
- Standard hermetic or molded 40-pin DIP package
- Temperature range $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ or $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
- Low power consumption - 15 mW
- Latched TRI-STATE ${ }^{\circledR}$ output
- Direct access to "comparator in" and "multiplexer out" for signal conditioning


## Block Diagram



| Absolute Maximum RatingS (Notes 1 and 2) |  |
| :--- | ---: |
| Supply Voltage $\left(\mathrm{V}_{\mathrm{CC}}\right)($ (Note 3$)$ | 6.5 V |
| Voltage at Any Pin | -0.3 V to $\left(\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}\right)$ |
| Except Control Inputs | -0.3 V to 15 V |
| Voltage at Control Inputs |  |
| (START, OE, CLOCK, ALE, EXPANSION CONTROL, |  |
| ADD A, ADD B, ADD C, ADD D) | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Storage Temperature Range | 875 mW |
| Package Dissipation at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | $300^{\circ} \mathrm{C}$ |

Operating Ratings (Notes 1 and 2 )

| Temperature Range (Note 1) | $T_{M I N} \leq T_{A} \leq T_{M A X}$ |
| :--- | ---: |
| ADC0816CJ | $-55^{\circ} \mathrm{C} \leq T_{A} \leq+125^{\circ} \mathrm{C}$ |
| ADC0816CCJ, ADC0816CCN, | $-40^{\circ} \mathrm{C} \leq T_{A} \leq+85^{\circ} \mathrm{C}$ |
| $\quad$ ADC0817CCN |  |
| Range of $V_{C C}$ (Note 1) | $4.5 V_{D C}$ to $6.0 V_{D C}$ |
| Voltage at Any Pin | $0 V$ to $V_{C C}$ |
| $\quad$ Except Control Inputs |  |
| Voltage at Controlinputs |  |
| (START, OE, CIOCK. ALE, EXPANSION CONTROL. |  |
| ADD A, ADD B, ADD C, ADD D) |  |

## Electrical Characteristics

Converter Specifications: $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}_{\mathrm{DC}}=\mathrm{V}_{\mathrm{REF}(+)}, \mathrm{V}_{\mathrm{REF}(-)}=\mathrm{GND}, \mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\text {COMPARATOR IN }}, \mathrm{T}_{\mathrm{MIN}} \leq \mathrm{T}_{\mathrm{A}} \leq \mathrm{T}_{\mathrm{MAX}}$ and $f_{C L K}=640 \mathrm{kHz}$ unless otherwise stated.


## Electrical Characteristics

Digital Levels and DC Specifications: ADC0816CJ $4.5 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CC}} \leq 5.5 \mathrm{~V},-55^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+125^{\circ} \mathrm{C}$ unless otherwise noted. ADC0816CCJ, ADC0816CCN, ADC0817CCN $4.75 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CC}} \leq 5.25 \mathrm{~V},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ unless otherwise noted.

| Parameter |  | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG MULTIPLEXER |  |  |  |  |  |  |
| $\mathrm{R}_{\text {ON }}$ | Analog Multiplexer ON Resistance | (Any Selected Channel) $\begin{aligned} & T_{A}=25^{\circ} \mathrm{C}, R_{L}=10 \mathrm{k} \\ & T_{A}=85^{\circ} \mathrm{C} \\ & T_{A}=125^{\circ} \mathrm{C} \end{aligned}$ |  | 1.5 | $\begin{aligned} & 3 \\ & 6 \\ & 9 \end{aligned}$ | $\begin{aligned} & \mathrm{k} \Omega \\ & \mathrm{k} \Omega \\ & \mathrm{k} \Omega \end{aligned}$ |
| $\Delta \mathrm{R}_{\text {ON }}$ | $\Delta$ ON Resistance Between Any 2 Channels | (Any Selected Channel) $R_{L}=10 \mathrm{k}$ |  | 75 |  | $\Omega$ |
| $\mathrm{l}_{\text {OFF }(+)}$ | OFF Channel Leakage Current | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \mathrm{~V}_{I N}=5 \mathrm{~V}, \\ & T_{A}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\text {MIN }} \text { to } \mathrm{T}_{\text {MAX }} \end{aligned}$ |  | 10 | $\begin{gathered} 200 \\ 1.0 \end{gathered}$ | $\begin{aligned} & \mathrm{nA} \\ & \mu \mathrm{~A} \end{aligned}$ |
| Ioff(-) | OFF Channel Leakage Current | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, V_{I N}=0, \\ & T_{A}=25^{\circ} \mathrm{C} \\ & T_{\text {MIN }} \text { to } T_{M A X} \end{aligned}$ | $\begin{array}{r} -200 \\ -1.0 \\ \hline \end{array}$ |  |  | $\begin{aligned} & \mathrm{nA} \\ & \mu \mathrm{~A} \end{aligned}$ |
| CONTROL INPUTS |  |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage |  | $\mathrm{V}_{\mathrm{CC}}-1.5$ |  |  | V |
|  | Logical "0" Input Voltage |  |  |  | 1.5 | V |
| $\mathrm{I}_{\text {IN(1) }}$ | Logical "1" Input Current (The Control Inputs) | $V_{\text {IN }}=15 \mathrm{~V}$ |  |  | 1.0 | $\mu \mathrm{A}$ |
| $I_{\text {IN(0) }}$ | Logical "0" Input Current (The Control Inputs) | $V_{\text {IN }}=0$ | - 1.0 |  |  | $\mu \mathrm{A}$ |
| Icc | Supply Current | $\mathrm{f}_{\mathrm{CLK}}=640 \mathrm{kHz}$ |  | 0.3 | 3.0 | mA |

Electrical Characteristics (Continued)
Digital Levels and DC Specifications: ADC0816CJ $-4.5 \mathrm{~V} \leqslant \mathrm{~V}_{C C} \leqslant 5.5 \mathrm{~V},-55^{\circ} \mathrm{C} \leqslant \mathrm{T}_{\mathrm{A}} \leqslant+125^{\circ} \mathrm{C}$ unless otherwise noted. ADC0816CCJ, ADC0816CCN, ADC0817CCN $-4.75 \mathrm{~V} \leqslant \mathrm{~V}_{\mathrm{CC}} \leqslant 5.25 \mathrm{~V},-40^{\circ} \mathrm{C} \leqslant+85^{\circ} \mathrm{C}$ unless otherwise noted.

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DATA OUTPUTS AND EOC (INTERRUPT) |  |  |  |  |  |  |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A}, \mathrm{~T}_{\mathrm{A}}=85^{\circ} \mathrm{C} \\ & \mathrm{I}_{\mathrm{O}}=-300 \mu \mathrm{~A}, \mathrm{~T}_{\mathrm{A}}=125^{\circ} \mathrm{C} \end{aligned}$ | $V_{C C}-0.4$ |  |  | V |
| $V_{\text {OUT(0) }}$ | Logical " 0 " Output Voltage | $\mathrm{l}_{0}=1.6 \mathrm{~mA}$ |  |  | 0.45 | V |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical "0" Output Voltage EOC | $\mathrm{l}_{\mathrm{O}}=1.2 \mathrm{~mA}$ |  |  | 0.45 | V |
| lout | TRI-STATE ${ }^{\oplus}$ Output Current | $\begin{aligned} & V_{O}=V_{C C} \\ & V_{O}=0 \end{aligned}$ | -3.0 |  | 3.0 | $\mu \mathrm{A}$ $\mu \mathrm{A}$ |

## Electrical Characteristics

Timing Specifications: $\mathrm{V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{REF}(+)}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{REF}(-)}=\mathrm{GND}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$ and $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted.

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {ws }}$ | Minimum Start Pulse Width | (Figure 5) |  | 100 | 200 | ns |
| ${ }^{\text {t wale }}$ | Minimum ALE Pulse Width | (Figure 5) |  | 100 | 200 | ns |
| $\mathrm{t}_{\text {s }}$ | Minimum Address Set-Up Time | (Figure 5) |  | 25 | 50 | ns |
| $t_{H}$ | Minimum Address Hold Time | (Figure 5) |  | 25 | 50 | ns |
| $t_{D}$ | Analog MUX Delay Time From ALE | $\mathrm{R}_{\mathrm{S}}=0 \Omega$ (Figure 5) |  | 1 | 2.5 | $\mu \mathrm{S}$ |
| $t_{\mathrm{H} 1}, \mathrm{t}_{\mathrm{HO}}$ | OE Control to Q Logic State | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}$ (Figure 8) |  | 125 | 250 | ns |
| $t_{1 H}, t_{O H}$ | OE Control to $\mathrm{Hi}-\mathrm{Z}$ | $\mathrm{C}_{\mathrm{L}}=10 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}$ (Figure 8) |  | 125 | 250 | ns |
| $\mathrm{t}_{\mathrm{c}}$ | Conversion Time | $\mathrm{f}_{\mathrm{c}}=640 \mathrm{kHz},($ Figure 5) $($ Note 7) | 90 | 100 | 116 | $\mu \mathrm{S}$ |
| $f_{c}$ | Clock Frequency |  | 10 | 640 | 1280 | kHz |
| $t_{\text {EOC }}$ | EOC Delay Time | (Figure 5) | 0 |  | $8+2 \mu \mathrm{~s}$ | Clock <br> Periods |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | At Control Inputs |  | 10 | 15 | pF |
| $\mathrm{C}_{\text {OUT }}$ | TRI-STATE ${ }^{\circledR}$ Output Capacitance | At TRI-STATE Outputs. (Note 7) |  | 10 | 15 | pF |

Note 1: Absolute maximum ratings are those values beyond which the life of the device may be impaired.
Note 2: All voltages are measured with respect to GND, unless otherwise specified.
Note 3: A zener diode exists, internally, from $V_{C C}$ to $G N D$ and has a typical breakdown voltage of $7 V_{D C}$.
Note 4: Two on-chip diodes are tied to each analog input which will forward conduct for analog input voltages one diode drop below ground or one diode drop greater than the $V_{C C}$ supply. The spec allows 100 mV forward bias of either diode. This means that as long as the analog $V_{\text {IN }}$ does not exceed the supply voltage by more than 100 mV , the output code will be correct. To achieve an absolute $0 \mathrm{~V}_{D C}$ to $5 \mathrm{~V}_{D C}$ input voltage range will therefore require a minimum supply voltage of $4.900 \mathrm{~V}_{\mathrm{DC}}$ over temperature variations, initial tolerance and loading.
Note 5: Total unadjusted error includes offset, full-scale, and linearity errors. See Figure 3. None of these A/Ds requires a zero or full-scale adjust. However, if an all zero code is desired for an analog input other than 0.0 V , or if a narrow full-scale span exists (for example: 0.5 V to 4.5 V full-scale) the reference voltages can be adjusted to achieve this. See Figure 13.
Note 6: Comparator input current is a bias current into or out of the chopper stabilized comparator. The bias current varies directly with clock frequency and has little temperature dependence (Figure 6). See paragraph 4.0.
Note 7: The outputs of the data register are updated one clock cycle before the rising edge of EOC.

## Functional Description

Multiplexer: The device contains a 16 -channel singleended analog signal multiplexer. A particular input channel is selected by using the address decoder. Table I shows the input states for the address line and the expansion control line to select any channel. The address is latched into the decoder on the low-to-high transition of the address latch enable signal.

TABLE I

| SELECTED <br> ANALOG CHANNEL | ADDRESS LINE |  |  | EXPANSION |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | D | C | B |  | CONTROL |
| IN0 | L | L | L | L | H |
| IN1 | L | L | L | H | H |
| IN2 | L | L | H | L | H |
| IN3 | L | L | H | H | H |
| IN4 | L | H | L | L | H |
| IN5 | L | H | L | H | H |
| IN6 | L | H | H | L | H |
| IN7 | L | H | H | H | H |
| IN8 | H | L | L | L | H |
| IN9 | H | L | L | H | H |
| IN10 | H | L | H | L | H |
| IN11 | H | L | H | H | H |
| IN12 | H | H | L | L | H |
| IN13 | H | H | L | H | H |
| IN14 | H | H | H | L | H |
| IN15 | H | H | H | H | H |
| All Channels OFF | X | X | X | X | L |

$X=$ don't care

Additional single-ended analog signals can be multiplexed to the AID converter by disabling all the multiplexer inputs using the expansion control. The additional external signals are connected to the comparator input and the device ground. Additional signal conditioning (i.e., prescaling, sample and hold, instrumentation amplification, etc.) may also be added between the analog input signal and the comparator input.

## CONVERTER CHARACTERISTICS

## The Converter

The heart of this single chip data acquisition system is its 8 -bit analog-to-digital converter. The converter is designed to give fast, accurate, and repeatable conversions over a wide range of temperatures. The converter is partitioned into 3 major sections: the 256R ladder network, the successive approximation register, and the comparator. The converter's digital outputs are positive true.

The 256R ladder network approach (Figure 1) was chosen over the conventional R/2R ladder because of its inherent monotonicity, which guarantees no missing digital codes. Monotonicity is particularly important in closed loop feedback control systems. A non-monotonic relationship can cause oscillations that will be catastrophic for the system. Additionally, the 256R network does not cause load variations on the reference voltage.
The bottom resistor and the top resistor of the ladder network in Figure 1 are not the same value as the remainder of the network. The difference in these resistors causes the output characteristic to be symmetrical with the zero and full-scale points of the transfer curve. The first output transition occurs when the analog signal has reached $+1 / 2$ LSB and succeeding output transitions occur every 1 LSB later up to full-scale.


FIGURE 1. Resistor Ladder and Switch Tree

## Functional Description (Continued)

The successive approximation register (SAR) performs 8 iterations to approximate the input voltage. For any SAR type converter, n-iterations are required for an $n$-bit converter. Figure 2 shows a typical example of a 3 -bit converter. In the ADC0816, ADC0817, the approximation technique is extended to 8 bits using the 256R network.

The A/D converter's successive approximation register (SAR) is reset on the positive edge of the start conversion (SC) pulse. The conversion is begun on the falling edge of the start conversion pulse. A conversion in process will be interrupted by receipt of a new start conversion pulse. Continuous conversion may be accomplished by tying the end-of-conversion (EOC) output to the SC input. If used in this mode, an external start conversion pulse should be applied after power up. End-of-conversion will go low between 0 and 8 clock pulses after the rising edge of start conversion.

The most important section of the A/D converter is the comparator. It is this section which is responsible for the ultimate accuracy of the entire converter. It is also the comparator drift which has the greatest influence on the repeatability of the device. A chopper-stabilized comparator provides the most effective method of satisfying all the converter requirements.

The chopper-stabilized comparator converts the DC input signal into an AC signal. This signal is then fed through a high gain AC amplifier and has the DC level restored. This technique limits the drift component of the amplifier since the drift is a DC component which is not passed by the AC amplifier. This makes the entire A/D converter extremely insensitive to temperature, long term drift and input offset errors.
Figure 4 shows a typical error curve for the ADC0816 as measured using the procedures outlined in AN-179.


FIGURE 2. 3-Bit A/D Transfer Curve


FIGURE 3. 3-Bit A/D Absolute Accuracy Curve


FIGURE 4. Typical Error Curve

Connection Diagram

Dual-In-Line Package


## Timing Diagram



FIGURE 5

## Typical Performance Characteristics



FIGURE 6. Comparator $I_{\mathbb{N}}$ vs $V_{I N}$ $\left(\mathrm{V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{REF}}=5 \mathrm{~V}\right)$


FIGURE 7. Multiplexer $R_{\text {ON }}$ vs $V_{\text {IN }}$ $\left(\mathrm{V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{REF}}=5 \mathrm{~V}\right.$ )

## TRI-STATE ${ }^{\circledR}$ Test Circuits and Timing Diagrams



$$
t_{H 1}, C_{L}=50 \mathrm{pF}
$$



$$
t_{\mathrm{HO}}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}
$$



FIGURE 8

## Applications Information

## OPERATION

### 1.0 Ratiometric Conversion

The ADC0816, ADC0817 is designed as a complete Data Acquisition System (DAS) for ratiometric conversion systems. In ratiometric systems, the physical variable being measured is expressed as a percentage of full-scale which is not necessarily related to an absolute standard. The voltage input to the ADC0816 is expressed by the equation

$$
\begin{equation*}
\frac{V_{I N}}{V_{t s}-V_{Z}}=\frac{D_{X}}{D_{\text {MAX }}-D_{\text {MIN }}} \tag{1}
\end{equation*}
$$

$\mathrm{V}_{\text {IN }}=$ Input voltage into the ADC0816
$V_{\text {fs }}=$ Full-scale voltage
$\mathrm{V}_{\mathrm{Z}}=$ Zero voltage
$D_{X}=$ Data point being measured
$D_{\text {MAX }}=$ Maximum data limit
$D_{\text {MIN }}=$ Minimum data limit

A good example of a ratiometric transducer is a potentiometer used as a position sensor. The position of the wiper is directly proportional to the output voltage which is a ratio of the full-scale voltage across it. Since the data is represented as a proportion of full-scale, reference requirements are greatly reduced, eliminating a large source of error and cost for many applications. A major advantage of the ADC0816, ADC0817 is that the input voltage range is equal to the supply range so the transducers can be connected directly across the supply and their outputs connected directly into the multiplexer inputs, (Figure 9).

Ratiometric transducers such as potentiometers, strain gauges, thermistor bridges, pressure transducers, etc., are suitable for measuring proportional relationships; however, many types of measurements must be referred to an absolute standard such as voltage or current. This means a system reference must be used which relates the full-scale voltage to the standard volt. For example, if $V_{C C}=V_{\text {REF }}=5.12 \mathrm{~V}$, then the full-scale range is divided into 256 standard steps. The smallest standard step is 1 LSB which is then 20 mV .

### 2.0 Resistor Ladder Limitations

The voltages from the resistor ladder are compared to the selected input 8 times in a conversion. These voltages are coupled to the comparator via an analog switch tree which is referenced to the supply. The voltages at the top, center and bottom of the ladder must be controlled to maintain proper operation.
The top of the ladder, $\operatorname{Ref}(+$ ), should not be more positive than the supply, and the bottom of the ladder, Ref( - ), should not be more negative than ground. The center of the ladder voltage must also be near the center of the supply because the analog switch tree changes from N -channel switches to P -channel switches. These limitations are automatically satisfied in ratiometric systems and can be easily met in ground referenced systems.

Figure 10 shows a ground referenced system with a separate supply and reference. In this system, the supply must be trimmed to match the reference voltage. For instance, if a 5.12 V reference is used, the supply should be adjusted to the same voltage within 0.1 V .


FIGURE 9. Ratiometric Conversion System

## Applications Information (Continued)

The ADC0816 needs less than a milliamp of supply current so developing the supply from the reference is readily accomplished. In Figure 11 a ground referenced system is shown which generates the supply from the reference. The buffer shown can be an op amp of sufficient drive to supply the milliamp of supply current and the desired bus drive, or if a capacitive bus is driven by the outputs a large capacitor will supply the transient supply current as seen in Figure 12. The LM301 is overcompensated to insure stability when loaded by the $10 \mu \mathrm{~F}$ output capacitor.

The top and bottom ladder voltages cannot exceed $\mathrm{V}_{\mathrm{Cc}}$ and ground, respectively, but they can be symmetrically less than $\mathrm{V}_{\mathrm{CC}}$ and greater than ground. The center of the ladder voltage should always be near the center of the supply. The sensitivity of the converter can be increased, (i.e., size of the LSB steps decreased) by using a symmetrical reference system. In Figure 13, a 2.5 V reference is symmetrically centered about $\mathrm{V}_{\mathrm{CC}} / 2$ since the same current flows in identical resistors. This system with a 2.5 V reference allows the LSB to be half the size of the LSB in a 5 V reference system.


FIGURE 10. Ground Referenced
Conversion System Using Trimmed Supply


FIGURE 11. Ground Referenced Conversion System with Reference Generating $\mathbf{V}_{\mathbf{C c}}$ Supply



FIGURE 13. Symmetrically Centered Reference

### 3.0 Converter Equations

The transition between adjacent codes N and $\mathrm{N}+1$ is given by:

$$
V_{I N}=\left\{\left(V_{R E F(+)}-V_{R E F(-)}\right)\left[\frac{N}{256}+\frac{1}{512}\right] \pm V_{T U E}\right\}+V_{R E F(-)}
$$

The center of an output code $N$ is given by:

$$
V_{I N}=\left\{\left(V_{R E F(+)}-V_{\operatorname{REF}(-)}\right)\left[\frac{N}{256}\right] \pm V_{\operatorname{TUE}}\right\}+V_{\text {REF }(-)}
$$

The output code N for an arbitrary input are the integers within the range:

$$
\begin{equation*}
N=\frac{V_{I N}-V_{\operatorname{REF}(-)}}{V_{\operatorname{REF}(+)}-V_{\operatorname{REF}(-)}} \times 256 \pm \text { Absolute Accuracy } \tag{4}
\end{equation*}
$$

where: $\mathrm{V}_{\mathbb{N}}=$ Voltage at comparator input
$V_{R E F(+)}=$ Voltage at $\operatorname{Ref}(+)$
$\mathrm{V}_{\text {REF (-) }}=$ Voltage at $\operatorname{Ref}(-)$
$V_{\text {TUE }}=$ Total unadjusted error voltage (typically
$\mathrm{V}_{\text {REF }(+)} \div 512$ )

### 4.0 Analog Comparator Inputs

The dynamic comparator input current is caused by the periodic switching of on-chip stray capacitances. These are connected alternately to the output of the resistor ladder/switch tree network and to the comparator input as part of the operation of the chopper stabilized comparator.

The average value of the comparator input current varies directly with clock frequency and with $\mathrm{V}_{\mathbb{I N}}$ as shown in Figure 6.

If no filter capacitors are used at the analog or comparator inputs and the signal source impedances are low, the comparator input current should not introduce converter errors, as the transient created by the capacitance discharge will die out before the comparator output is strobed.

If input filter capacitors are desired for noise reduction and signal conditioning they will tend to average out the dynamic comparator input current. It will then take on the characteristics of a DC bias current whose effect can be predicted conventionally. See AN-258 for further discussion.

## Typical Application



* Address latches needed for 8085 and SC/MP interfacing the ADC0816, 17 to a microprocessor


## Microprocessor Interface Table

| PROCESSOR | $\overline{\text { READ }}$ | WRITE | INTERRUPT (COMMENT) |
| :---: | :---: | :---: | :---: |
| 8080 | $\overline{\text { MEMR }}$ | $\overline{\text { MEMW }}$ | INTR (Thru RST Circuit) |
| 8085 | $\overline{\mathrm{RD}}$ | $\overline{\mathrm{WR}}$ | INTR (Thru RST Circuit) |
| Z-80 | $\overline{\mathrm{RD}}$ | $\overline{\text { WR }}$ | $\overline{\mathrm{INT}}$ (Thru RST Circuit, Mode 0) |
| SCIMP | NRDS | NWDS | SA (Thru Sense A) |
| 6800 | VMA ${ }^{\text {¢ } 2 \cdot R W ~}$ | VMA ${ }^{+} 2 \cdot \overline{\mathrm{R} W}$ | $\overline{\mathrm{IRQA}}$ or $\overline{\mathrm{IRQB}}$ (Thru PIA) |

## Ordering Information

| TEMPERATURE RANGE |  | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |  | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| :---: | :---: | :---: | :---: | :---: |
| Error | $\pm 1 / 2$ Bit Unadjusted | ADC0816CCN | ADC0816CCJ | ADC0816CJ |
|  | $\pm 1$ Bit Unadjusted | ADC0817CCN |  |  |
| Package Outline |  | N40A Molded DIP | J40A Hermetic DIP | J40A Hermetic DIP |

## General Description

The ADC3511 and ADC3711 (MM74C937-1, MM74C9381) monolithic $A / D$ converter circuits are manufactured using standard complementary MOS (CMOS) technology. A pulse modulation analog-to-digital conversion technique is used and requires no external precision components. In addition, this technique allows the use of a reference voltage that is the same polarity as the input voltage.

One 5V (TTL) power supply is required. Operating with an isolated supply allows the conversion of positive as well as negative voltages. The sign of the input voltage is automatically determined and indicated on the sign pin. If the power supply is not isolated, only one polarity of voltage may be converted.

The conversion rate is set by an internal oscillator. The frequency of the oscillator can be set by an external RC network or the oscillator can be driven from an external frequency source. When using the external RC network, a square wave output is available.

The ADC3511 and ADC3711 have been designed to provide addressed BCD data and are intended for use with microprocessors and other digital systems. BCD digits are selected on demand via 2 Digit Select (D0, D1) inputs. Digit Select inputs are latched by, a low-to-high transition on the Digit Latch Enable (DLE) input and will remain latched as long as DLE remains high. A start
conversion input and a conversion complete output are included on both the ADC3511 and the ADC3711.

## Features

- Operates from single 5V supply
- ADC3511 converts 0 to $\pm 1999$ counts
- ADC3711 converts 0 to $\pm 3999$ counts
- Addressed BCD outputs
- No external precision components necessary
- Easily interfaced to microprocessors or other digital systems
- Medium speed-200 ms/conversion
- TTL compatible
- Internal clock set with RC network or driven externally
m Overflow indicated by hex "EEEE" output reading as well as an overflow output


## Applications

- Low cost analog-to-digital converter
- Eliminate analog multiplexing by using remote $A / D$ converters
■ Convert analog transducers (temperature, pressure, displacement, etc.) to digital transducers



## Absolute Maximum Ratings (Note 1)

Voltage at Any Pin
Operating Temperature Range ( $T_{A}$ )
Package Dissipation at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
Operating $V_{C C}$ Range
Absolute Maximum VCC
Storage Temperature Range
Lead Temperature (Soldering, 10 seconds)
DC Electrical Characteristics ADC3511CC, ADC3711CC
$4.75 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CC}} \leq 5.25 \mathrm{~V},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$, unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | $\begin{aligned} & \text { TYP } \\ & \text { (Note 2) } \end{aligned}$ | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| VIN(1) | Logical "1" Input Voltage (Except fiN) |  | $V_{C C}{ }^{-1} .5$ |  |  | V |
| VIN(0) | Logical "0" Input Voltage (Except fiN) |  |  |  | 1.5 | V |
| VIN(1) | Logical " 1 " Input Voltage (fin) |  | $\mathrm{V}_{C C}{ }^{-0.6}$ |  |  | V |
| VIN(0) | Logical " 0 " Input Voltage (fin) |  |  |  | 0.6 | V |
| VOUT(1) | Logical " 1 " Output Voltage (Except $2^{0}, 2^{1}, 2^{2}, 2^{3}$ ) | $\mathrm{I}^{\prime}=360 \mu \mathrm{~A}$ | $\mathrm{V}_{\mathrm{CC}}{ }^{-0.4}$ |  |  | V , |
| VOUT(1) | Logical " 1 " Output Voltage $\left(2^{0}, 2^{1}, 2^{2}, 2^{3}\right)$ | $\mathrm{I}^{\prime}=360 \mu \mathrm{~A}$ | $V_{C C}{ }^{-1.0}$ |  |  | V |
| VOUT(0) | Logical "0" Output Voltage | $\mathrm{I}_{\mathrm{O}}=1.6 \mathrm{~mA}$ |  |  | 0.4 | $V$ |
| IIN(1) | Logical " 1 " Input Current (SC, DLE, D0, D1) | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {CC }}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| IIN(0) | Logical " 0 " Input Current (SC, DLE, D0, D1) | $V_{\text {IN }}=0 V$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| ICC | Supply Current | All Outputs Open |  | 0.5 | 5.0 | mA |

## AC Electrical Characteristics ADC3511CC, ADC3711CC

$V_{C C}=5 V ; T_{A}=25^{\circ} \mathrm{C} ; C_{L}=50 \mathrm{pF} ; \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$; unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | TYP <br> (Note 2) | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| fosc <br> fin <br> fCONV | Oscillator Frequency <br> Clock Frequency <br> Conversion Rate |  |  | 0.6/RC |  | Hz |
|  |  |  | 100 |  | 640 | kHz |
|  |  | ADC3511CC |  | in/64,512 |  | conversions/sec |
|  |  | ADC3711CC |  | IN/129,02 |  | conversions/sec |
| tSCPW | Start Conversion Pulse Width |  | 200 |  | DC | ns |
| ${ }^{\text {tpdo }}$, $\mathrm{t}_{\mathrm{pd} 1}$ | Propagation Delay DO, D1, to $2^{0}, 2^{1}, 2^{2}, 2^{3}$ | $D L E=0 V$ |  | 2.0 | 5.0 | $\mu \mathrm{s}$ |
| ${ }_{\text {t }}^{\text {pdo }}$, $\mathrm{t}_{\text {pd1 }}$ | Propagation Delay DLE to $2^{0}, 2^{1}, 2^{2}, 2^{3}$ |  |  | 2.0 | 5.0 | $\mu \mathrm{s}$ |
| ${ }^{\text {tSET-UP }}$ | Set-Up Time D0, D1, to DLE | $\mathrm{t}_{\text {HOLD }}=0 \mathrm{~ns}$ |  | 100 | 200 | ns |
| tPWDLE | Minimum Pulse Width Digit Latch Enable (Low) |  |  | 100 | 200 | ns |

Converter Characteristics ADC3511CC, ADC3711CC $4.75 \mathrm{~V} \leq \mathrm{V} C \mathrm{C} \leq 5.25 \mathrm{~V} ;-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$, $\mathrm{f}_{\mathrm{C}}=5$ conv. $/ \mathrm{sec}$ (ADC3511CC); 2.5 conv./sec (ADC3711CC); unless otherwise specified.

| PARAMETER |  | CONDITIONS | MIN | TYP <br> (Note 2) | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Non-Linearity | $V_{I N}=0-2 V$ Full Scale <br> VIN $=0-200 \mathrm{mV}$ Full Scale | -0.05 | $\pm 0.025$ | +0.05 | \% of Full-Scale <br> (Note 3) |
|  | Quantization Error |  | -1 |  | +0 | Counts |
|  | Offset Error | $V_{\text {IN }}=0 \mathrm{~V}$ | -0.5 | +1.0 | +3.0 | $\begin{array}{r} \mathrm{mV} \\ \text { (Note 4) } \end{array}$ |
| , | Rollover Error |  | -0 |  | +0 | Counts |
| $\mathrm{V}_{\text {IN }}$, $\mathrm{V}_{\text {IN }}$ - | Analog Input Current | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | -5 | $\pm 1$ | +5 | nA |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditionsfor actual device operation.
Note 2: All typicals are given for $T_{A}=25^{\circ} \mathrm{C}$.
Note 3: For the ADC3511CC: full-scale $=1999$ counts; therefore $0.025 \%$ of full-scale $=1 / 2$ count and $0.05 \%$ of full-scale $=1$ count. For the ADC3711CC: full-scale $=3999$ counts; therefore $0.025 \%$ of full-scale $=1$ count and $0.05 \%$ of full-scale $=2$ count.
Note 4: For full-scale $=2.000 \mathrm{~V}: 1 \mathrm{mV}=1$ count for the ADC3511CC; $1 \mathrm{mV}=2$ counts for the ADC3711CC.
Block Diagram

$$
\text { ADC3511 } 3 \text { 1/2-Digit A/D (*ADC3711 } 3 \text { 3/4-Digit A/D) }
$$



## Applications Information

## THEORY OF OPERATION

A schematic for the analog loop is shown in Figure 1. The output of SW1 is either at VREF or zero volts, depending on the state of the $D$ flip-flop. If $Q$ is at a high level, $\mathrm{V}_{\text {OUT }}=\mathrm{V}_{\text {REF }}$ and if Q is at a low level VOUT $=0 \mathrm{~V}$. This voltage is then applied to the low pass filter comprised of R1 and C1. The output of this filter, $\mathrm{V}_{\mathrm{FB}}$, is connected to the negative input of the comparator, where it is compared to the analog input voltage, VIN. The output of the comparator is connected to the $D$ input of the D flip-flop. Information is then transferred from the D input to the Q and $\overline{\mathrm{Q}}$ outputs on the positive edge of clock. This loop forms an oscillator whose duty cycle is precisely related to the analog input voltage, VIN.

An example will demonstrate this relationship. Assume the input voltage is equal to 0.500 V . If the Q output of the $D$ flip-flop is high then $V_{\text {OUT }}$ will equal $V_{\text {REF }}$ $(2.000 \mathrm{~V})$ and $V_{F B}$ will charge toward 2 V with a time constant equal to R1C1. At some time $V_{F B}$ will exceed 0.500 V and the comparator output will switch to 0 V . At the next clock rising edge the $Q$ output of the $D$ flipflop will switch to ground, causing VOUT to switch to 0 V . At this time, $\mathrm{V}_{\mathrm{FB}}$ will start discharging toward OV with a time constant R1C1. When VFB is less than 0.5 V the comparator output will switch high. On the rising edge of the next clock the Q output of the D flip-flop will switch high and the process will repeat. There exists at the output of SW1 a square wave pulse train with positive amplitude V , REF and negative amplitude $O V$.

The $D C$ value of this pulse train is:

$$
V_{O U T}=V_{\text {REF }} \frac{t_{O N}}{\text { tON }+ \text { toFF }}=V_{\text {REF }} \text { (duty cycle) }
$$

The lowpass filter will pass the DC value and then:

$$
V_{F B}=V_{\text {REF }} \text { (duty cycle) }
$$

Since the closed loop system will always force VFB to equal $\mathrm{V}_{\text {IN }}$, we can then say that:

$$
\left.V_{I N}=V_{F B}=V_{\text {REF }} \text { (duty cycle }\right)
$$

or

$$
\frac{V_{\text {IN }}}{V_{\text {REF }}}=\text { (duty cycle) }
$$

The duty cycle is logically ANDed with the input frequency $f i N$. The resultant frequency $f$ equals:

$$
f=(\text { duty cycle }) \times(f, \mathcal{N})
$$

Frequency $f$ is accumulated by counter no. 1 for a time determined by counter no. 2. The count contained in counter no. 1 is then:

$$
\begin{aligned}
(\text { count }) & =\frac{f}{(f \mid N) / N}=\frac{(\text { duty cycle) } \times(f(N)}{(f \mid N) / N} \\
& =\frac{V_{I N}}{V_{R E F}} \times N
\end{aligned}
$$

For the ADC3511 N=2000.
For the $\operatorname{ADC} 3711 \mathrm{~N}=4000$.

$V_{\text {IN }}=V_{\text {FB }}=V_{\text {REF }} \times$ (duty cycle)
$f=$ (duty cycle) $\times f_{I N}$
Count in counter no. $1=\frac{f}{f_{I N} / N}=\frac{\left(\text { duty cycle) } \times f_{I N}\right.}{f_{I N} / N}=\frac{V_{I N}}{V_{\text {REF }}} \times N$
FIGURE 1. Analog Loop Schematic Pulse Modulation A/D Converter

## GENERAL INFORMATION

The timing diagram, shown in Figure 2, gives operation for the free running mode. Free running operation is obtained by connecting the Start Conversion input to logic " 1 " ( $V_{C C}$ ). In this mode the analog input is continuously converted and the digit latches are updated at a rate equal to $64,512 \times 1 / \mathrm{f} / \mathrm{N}$ for the ADC3511, or 129,024 for the ADC3711.

The rising edge of the Conversion Complete output indicates that new information has been transferred from the internal counter to the digit latches. This information will remain in the digit latches until the next low-to-high transition of the Conversion Complete output. A logic " 1 " will be maintained on the Conversion Complete output for a time equal to $64 \times 1 / \mathrm{fiN}$ on the ADC3511, or $128 \times 1 / \mathrm{f}_{\mathrm{I}} \mathrm{N}$ on the ADC3711.

Figure 3 gives the operation using the Start Conversion input. It is important to note that the Start Conversion input and Conversion Complete output do not influence the actual analog-to-digital conversion in any way. Internally the ADC3511 and ADC3711 are always continuously converting the analog voltage present at their inputs. The Start Conversion input is used to control the transfer of information from the internal counter to the digit latches.

An RS latch on the Start Conversion input allows a broad range of input pulse widths to be used on this signal. As shown in Figure 3, the Conversion Complete output goes to a logic " 0 " on the rising edge of the Start Conversion pulse and goes to a logic " 1 " some time later when the new conversion is transferred from the internal counter to the display latch. Since the Start Conversion pulse can occur at any time during the conversion cycle, the amount of time from Start Conversion to Conversion Complete will vary. The maximum time is $64,512 \times 1 / \mathrm{f} / \mathrm{N}(129,024 \times 1 / \mathrm{f} / \mathrm{N}$ for the ADC3711) and the minimum time is $256 \times 1 / \mathrm{f} / \mathrm{N}$ ( 512 $\times 1 / \mathrm{fIN}$ for the ADC3711).

## SYSTEM DESIGN CONSIDERATIONS

The ADC3511 and ADC3711 have reduced the problem of high resolution, high accuracy analog-to-digital conversion to nearly the level of simplicity, economy, and compactness usually associated with digital logic circuitry. However, they are truly high precision analog devices, and require the same kind of design considerations given to all analog circuits. While great care has been taken in the design of the ADC3511 and ADC3711 to make their application as easy as possible, in order to utilize them to their full performance potential, good grounding, power supply distribution, decoupling, and regulation techniques should be exercised.


FIGURE 2. Conversion Cycle Timing Diagram for Free Running Operation (Times Shown in Parentheses are for the ADC3711)


FIGURE 3. Conversion Cycle Timing Diagram Operating with Start Conversion Input

| DIGIT SELECT INPUTS |  | SELECTED DIGIT |  |
| :---: | :---: | :---: | :--- |
| DLE | D1 |  |  |
| L | L | L | Digit 0 (LSD) |
| L | L | H | Digit 1 |
| L | H | L | Digit 2 |
| L | H | H | Digit 3 (MSD) |
| H | X | X | Unchanged |

$L=$ Low logic level
$H=$ High logic level
X = Irrelevant logic level

The value of the Selected Digit is presented at the $2^{3}, 2^{2}, 2^{1}$ and $2^{0}$ outputs in BCD format.

Note 1: If the value of a digit changes while it is selected, that change will be reflected at the outputs.
Note 2: An overflow condition will be indicated by a high level on the OVERFLOW output ( pin 5 ) and E16 in all digits.
Note 3: The sign of the input voltage, when these devices are operated in the bipolar mode, is indicated by the SIGN output (pin 8). A high level indicates a positive voltage, a low level a negative.

## Timing Diagrams



## Typical Applications

Figure 4 shows the ADC3511 and ADC3711 connected to convert 0 to +2.000 volts full scale operating from a non-isolated power supply. (Note that the ADC3511 converts 0 to +1999 counts full scale, while the ADC3711 converts 0 to +3999 counts full scale.) In this configuration the SIGN output (pin 8) should be ignored. Higher voltages can, of course, be converted by placing fixed dividers in the inputs, while lower voltages can be converted by placing fixed dividers in the feedback loop, as shown in Figure 6.

Figures 5 and 6 show systems operating with isolated supplies that will convert both polarities of inputs. 60 Hz common-mode noise can become a problem in these
configurations, so shielded transformers have been shown in the figures. The necessity for, and the type of shielding needed depends on the performance requirements, and the actual applications.

The filter capacitors connected to VFB (pin 12) and $^{\text {1 }}$ $V_{\text {FILTER ( }}$ (pin 11) should be of a low leakage variety. In the examples shown every 1.0 nA of leakage will cause approximately 0.1 mV error $\left(1.0 \times 10^{-9} \mathrm{~A} \times\right.$ $100 \mathrm{k} \Omega=0.1 \mathrm{mV}$ ). If the currents in both capacitors are exactly equal however, little error will result since the source impedances driving both capacitors are approximately matched.

## Typical Applications (Continued)




Note 1: All resistors $1 / 4$ watt, and $\pm 5 \%$, unless otherwise specified Note 2: All capacitors $\pm 10 \%$.
Note 3: Low leakage capacitor.
Note 4:

$$
R_{3}=\frac{R 1 R 2}{R 1+R 2}: 25 \Omega 2 .
$$

FIGURE 5. 3 1/2-Digit A/D; $\pm 1999$ Counts, $\pm 2.000$ Volts Full Scale (3 3/4-Digit A/D; $\pm 3999$ Counts, $\pm 2.000$ Volts Full Scale)


Note 1: All resistors $1 / 4$ watt, and $\pm 5 \%$, unless otherwise specified.
Note 2: All capacitors $\pm 10 \%$.
Note 3: Low leakage capacitor.
Note 4: $\quad R_{3}=\frac{R 1 R 2}{R 1+R 2} \pm 50 \Omega$.
Note 5: R4 $=900 \mathrm{k} \pm 1 \%$ for the $\mathrm{ADC} 3511 \mathrm{CC}, 200.0 \mathrm{mV}$ Full-Scale. $R 4=400 \mathrm{k} \pm 1 \%$ for the ADC3711CC, 400.0 mV Full-Scale.

FIGURE 6. 3 1/2-Digit A/D; $\pm 1999$ Counts, $\pm 200.0 \mathrm{mV}$ Full Scale (3 3/4-Digit A/D; $\pm 3999$ Counts, $\pm 400.0 \mathrm{mV}$ Full-Scale)

National
Semiconductor

## ADD3501 3½ Digit DVM with Multiplexed 7-Segment Output

## General Description

The ADD3501 (MM74C935-1) monolithic DVM circuit is manufactured using standard complementary MOS (CMOS) technology. A pulse modulation analog-todigital conversion technique is used and requires no external precision components. In addition, this technique allows the use of a reference voltage that is the same polarity as the input voltage.

One 5V (TTL) power supply is required. Operating with an isolated supply allows the conversion of positive as well as negative voltages. The sign of the input voltage is automatically determined and output on the sign pin. If the power supply is not isolated, only one polarity of voltage may be converted.

The conversion rate is set by an internal oscillator. The frequency of the oscillator can be set by an external RC network or the oscillator can be driven from an external frequency source. When using the external RC network, a square wave output is available. It is important to note that great care has been taken to synchronize digit multiplexing with the $A / D$ conversion timing to eliminate noise due to power supply transients.

The ADD3501 has been designed to drive 7-segment multiplexed LED displays directly with the aid of external digit buffers and segment resistors. Under condition of overrange, the overflow output will go high and the display will read +OFL or -OFL, depending on whether the input voltage is positive or negative. In addition to this, the most significant digit is blanked when zero.

A start conversion input and a conversion complete output are included on all 4 versions of this product.

## Features

- Operates from single 5 V supply
- Converts 0 V to $\pm 1.999 \mathrm{~V}$
- Multiplexed 7 -segment
- Drives segments directly
- No external precision component necessary
- Accurácy specified over temperature
- Medium speed - $200 \mathrm{~ms} /$ conversion
- Internal clock set with RC network or driven externally
- Overrange indicated by +OFL or -OFL display reading and OFLO output
- Analog inputs in applications shown can withstand $\pm 200$ Volts


## Applications

- Low cost digital power supply readouts
- Low cost digital multimeters
- Low cost digital panel meters
- Eliminate analog multiplexing by using remote $A / D$ converters
- Convert analog transducers (temperature, pressure, displacement, etc.) to digital transducers


## Connection Diagram



## Absolute Maximum Ratings (Note 1)

Voltage at Any Pin
Operating Temperature Range ( $\mathrm{T}_{\mathrm{A}}$ )
Package Dissipation at $T_{A}=25^{\circ} \mathrm{C}$
-0.3 V to $\mathrm{V}_{\mathrm{Cc}}+0.3 \mathrm{~V}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
800 mW
derate at $\theta_{J A(M A X)}=125^{\circ} \mathrm{C} /$ Watt above $T_{A}=25^{\circ} \mathrm{C}$
Operating $V_{C C}$ Range
4.5 V to 6.0 V

Absolute Maximum $\mathrm{V}_{\mathrm{cc}}$
6.5 V

Lead Temperature (Soldering, 10 seconds)
Storage Temperature Range $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$

Electrical Characteristics $4.75 \mathrm{~V} \leqslant \mathrm{~V}_{\mathrm{CC}} \leqslant 5.25 \mathrm{~V},-40^{\circ} \mathrm{C} \leqslant \mathrm{T}_{\mathrm{A}} \leqslant+85^{\circ} \mathrm{C}$, unless otherwise specified.
ADD3501

|  | PARAMETER | CONDITIONS | MIN | TYP (2) | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage |  | $\mathrm{V}_{\mathrm{cc}}-1.5$ |  |  | V |
| $\mathrm{V}_{\text {IN }}(0)$ | Logical "0' Input Voltage |  |  |  | 1.5 | V |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical "0" Output Voltage (All Digital Outputs except Digit Outputs) | $\mathrm{I}_{\mathrm{O}}=1.1 \mathrm{~mA}$ |  |  | 0.4 | V |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical "0" Output Voltage (Digit Outputs) | $\mathrm{I}_{0}=0.7 \mathrm{~mA}$ |  |  | 0.4 | V |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage (All Segment Outputs) | $\begin{aligned} & I_{\mathrm{O}}=50 \mathrm{~mA} @ T_{J}=25^{\circ} \mathrm{C} V_{\mathrm{cc}}=5 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{O}}=30 \mathrm{~mA} @ T_{J}=100^{\circ} \mathrm{C} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{cc}}-1.6 \\ & \mathrm{~V}_{\mathrm{cc}}-1.6 \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{cc}}-1.3 \\ & \mathrm{~V}_{\mathrm{cc}}-1.3 \end{aligned}$ |  | V |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical " 1 " Output Voltage (All Digital Outputs except Segment Outputs) | $\begin{aligned} & \mathrm{I}_{\mathrm{O}}=500 \mu \mathrm{~A} \text { (Digit Outputs) } \\ & \mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A} \text { (Conv. Complete, } \\ & +/-, \text { Oflo Outputs) } \end{aligned}$ | $\mathrm{V}_{\mathrm{cc}}-0.4$ |  |  | V |
| $\mathrm{I}_{\text {SOURCE }}$ | Output Source Current (Digit Outputs) | $\mathrm{V}_{\text {OU.T }}=1.0 \mathrm{~V}$ | 2.0 |  |  | mA |
| $\mathrm{I}_{\text {IN }(1)}$ | Logical "1" Input Current (Start Conversion) | $V_{\text {IN }}=1.5 \mathrm{~V}$ |  | . | 1.0 | $\mu \mathrm{A}$ |
| $I_{\text {IN }(0)}$ | L_ogical " 0 " Input Current (Start Conversion) | $V_{\text {IN }}=0 \mathrm{~V}$ | -1.0 |  |  | $\mu \mathrm{A}$ |
| $I_{\text {cc }}$ | Supply Current | Segments and Digits Open |  | 0.5 | 10 | : mA |
| - | Oscillator Frequency |  |  | 0.6/RC |  | kHz |
| $\mathrm{f}_{\mathrm{IN}}$ | Clock Frequency |  | 100 |  | 640 | kHz |
| $\mathrm{f}_{\mathrm{C}}$ | Conversion Rate |  |  | $\mathrm{f}_{\text {IN }} / 64,512$ |  | conv./sec |
| $\mathrm{f}_{\text {mux }}$ | Digit Mux Rate |  |  | $\mathrm{f}_{\text {IN }} / 256$ |  | Hz |
| $t_{\text {BLANK }}$ | Inter Digit Blanking Time | , |  | $1 /\left(32 \mathrm{f}_{\mathrm{M}} \mathrm{UX}\right.$ ) |  | sec |
| $\mathrm{t}_{\text {SCPW }}$ | Start Conversion Pulse Width |  | 200 |  | DC | ns |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: All typicals given for $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.

## Electrical Characteristics ADD3501

$\mathrm{t}_{\mathrm{C}}=5$ conversions/second, $0^{\circ} \mathrm{C} \leqslant \mathrm{T}_{\mathrm{A}} \leqslant 70^{\circ} \mathrm{C}$, unless otherwise specified.

| Non-Linearity | $V_{I N}=0-2 \mathrm{~V}$ Full Scale <br> $V_{I N}=0-200 \mathrm{mV}$ Full Scale | -0.05 | $\pm 0.025$ | +0.05 | $\%$ of <br> full scale |
| :--- | :--- | :---: | :---: | :---: | :---: |
| Quantization Error |  | -1 |  | +0 | counts |
| Offset Error, $\mathrm{V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.5 | +1.5 | +3 | mV |
| Rollover Error | -0 |  | +0 | counts |  |
| Analog Input Current <br> $\left(\mathrm{V}_{1 N^{+}}, \mathrm{V}_{1 \mathrm{~N}^{-}}\right)$ | $T_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | -5 | $\pm 0.5$ | +5 | nA |

## block diagram



## Theory of Operation

A schematic for the analog loop is shown in figure 1. The output of SW1 is either at $\mathrm{V}_{\text {REF }}$ or zero volts, depending on the state of the $D$ flip-flop. If $Q$ is at a high level $\mathrm{V}_{\text {OUT }}=\mathrm{V}_{\text {REF }}$ and if Q is at a low level $\mathrm{V}_{\text {OUT }}$ $=0 \mathrm{~V}$. This voltage is then applied to the low pass filter comprised of R 1 and C 1 . The output of this filter, $\mathrm{V}_{\mathrm{FB}}$, is connected to the negative input of the comparator, where it is compared to the analog input voltage, $\mathrm{V}_{1 \mathrm{~N}}$. The output of the comparator is connected to the D input of the $D$ flip-flop. Information is then transferred from the D input to the Q and Q outputs on the positive edge of clock. This loop forms an oscillator whose duty cycle is precisely related to the analog input voltage, $\mathrm{V}_{\text {IN }}$.

An example will demonstrate this relationship. Assume the input voltage is equal to 0.500 V . If the Q output of the $D$ flip-flop is high then $V_{\text {OUT }}$ will equal $V_{\text {REF }}$ $(2.000 \mathrm{~V})$ and $\mathrm{V}_{\mathrm{FB}}$ will charge toward 2 V with a time constant equal to $\mathrm{R}_{1} \mathrm{C}_{1}$. At some time $\mathrm{V}_{\mathrm{FB}}$ will exceed 0.500 V and the comparator output will switch to 0 V . At the next clock rising edge the Q output of the D flipflop will switch to ground, causing $V_{\text {OUt }}$ to switch to $O V$. At this time $V_{F B}$ will start discharging toward $O V$ with a time constant $R_{1} C_{1}$. When $V_{F B}$ is less than 0.5 V the comparator output will switch high. On the rising edge of the next clock the Q output of the D flip-flop will switch high and the process will repeat. There exists at the output of SW1 a square wave pulse train with positive amplitude $\mathrm{V}_{\text {REF }}$ and negative amplitude OV .

The $D C$ value of this pulse train is:

$$
V_{O U T}=V_{R E F}\left(\frac{T_{O N}}{T_{O N}+T_{O F F}}\right)=V_{\text {REF }} \text { (duty cycle) }
$$

The lowpass filter will pass the DC value and then:

$$
V_{F B}=V_{\text {REF }} \text { (duty cycle) }
$$

Since the closed loop system will always force $\mathrm{V}_{\mathrm{FB}}$ to equal $V_{\text {IN }}$, we can then say that:

$$
V_{I N}=V_{F B}=V_{\text {REF }} \text { (duty cycle) }
$$

or

$$
\frac{V_{I N}}{V_{R E F}}=\text { (duty cycle) }
$$

The duty cycle is logically ANDed with the input frequency $f_{I N}$. The resultant frequency $f$ equals:

$$
f=\text { (duty cycle) } \times \text { (clock) }
$$

Frequency $f$ is accumulated by counter no. 1 for a time determined by counter no. 2. The count contained in counter no. 1 is then:

$$
\begin{aligned}
(\text { count }) & =\frac{f}{(\text { clock }) / \mathrm{N}}=\frac{(\text { duty cycle) } \times \text { (clock) }}{(\text { clock }) / \mathrm{N}} . \\
& =\frac{V_{I N}}{V_{\text {REF }}} \times N
\end{aligned}
$$

For the ADD3501, $\mathrm{N}=2000$.

## Schematic Diagram



Figure 1. Analog Loop Schematic
Pulse Modulation A/D Converter

## general information

The timing diagram, shown in figure 2, gives operation for the free running mode. Free running operation is obtained by connecting the Start Conversion input to logic " 1 " $\left(V_{\mathrm{cc}}\right)$. In this mode the analog input is continuously converted and the display is updated at a rate equal to $64,512 \times 1 / \mathrm{f}_{\mathrm{IN}}$.

The rising edge of the Conversion Complete output indicates that new information has been transferred from the internal counter to the display latch. This information will remain in the display latch until the next low-to-high transition of the Conversion Complete output. A logic " 1 " will be maintained on the Conversion Complete output for a time equal to $64 \times 1 / \mathrm{f}_{\mathrm{IN}}$.

Figure 3 gives the operation using the Start Conversion input. It is important to note that the Start Conversion input and Conversion Complete output do not influence the actual analog-to-digital conversion in any way.

Internally the ADD3501 is always continuously converting the analog voltage present at its inputs. The Start Conversion input is used to control the transfer of information from the internal counter to the display latch.

An RS latch on the Start Conversion input allows a broad range of input pulse widths to be used on this signal. As shown in figure 3, the Conversion Complete output goes to a logic " 0 " on the rising edge of the Start Conversion pulse and goes to a logic " 1 " some time later when the new conversion is transferred from the internal counter to the display latch. Since the Start Conversion pulse can occur at any time during the conversion cycle, the amount of time from Start Conversion to Conversion Complete will vary. The maximum time is $64,512 \times 1 / \mathrm{f}_{\mathrm{IN}}$ and the minimum time is $256 \times 1 / f_{I N}$.

## Timing Waveforms



Figure 2. Conversion Cycle Timing Diagram for Free Running Operation

# CONVERSION CYCLE 

 (INTERNAL SIGNAL)START CONVERSIONi: $\quad \square \square$


Figure 3. Conversion Cycle Timing Diagram Operating with Start Conversion Input

## Applications

## SYSTEM DESIGN CONSIDERATIONS

Perhaps the most important thing to consider when designing a system using the ADD3501 is power supply noise on the $V_{C c}$ and ground lines. Because a single power supply is used and currents in the 300 mA range are being switched, good circuit layout techniques cannot be overemphasized. Great care has been exercised in the design of the ADD3501 to minimize these problems but poor printed circuit layout can negate these features.

Figures 4, 5, and 6 show schematics of DVM systems. An attempt has been made to show, on these schematics, the proper distribution for ground and $\mathrm{V}_{\mathrm{cc}}$. To help isolate digital and analog portions of the circuit, the analog $V_{C C}$ and ground have been separated from the digital $V_{C C}$ and ground. Care must be taken to eliminate high current from flowing in the analog $\mathrm{V}_{\mathrm{Cc}}$ and ground wires. The most effective method of accomplishing this is to use a single ground point and a single $\mathrm{V}_{\mathrm{Cc}}$ point where all wires are brought together. In addition to this the conductors must be of sufficient size to prevent significant voltage drops.

To prevent switching noise from causing jitter problems, a voltage regulator with good high frequency response is necessary. The LM309 and the LM340-5 voltage regulators both function well and are shown in figures 4,5 , and 6 . Adding more filtering than is shown will in general increase the jitter rather than decrease it. The
most important characteristic of transients on the $\mathrm{V}_{\mathrm{Cc}}$ line is the duration of the transient and not its amplitude.

Figure 4 shows a DPM system which converts $O V$ to 1.999 V operating from a non-isolated power supply. In this configuration the sign output could be + (logic " 1 ") or - (logic " 0 ") and it should be ignored. Higher voltages could be converted by placing a fixed divider on the input; lower voltages could be converted by placing a fixed divider on the feedback, as shown in figure 6.

Figures 5 and 6 show systems operating with an isolated supply that will convert positive and negative inputs. 60 Hz common mode input becomes a problem in this configuration and a transformer with an electrostatic shield between primary and secondary windings is shown. The necessity for using a shielded transformer depends on the performance requirements and the actual application.

The filter capacitors connected to $\mathrm{V}_{\mathrm{FB}}$ (pin 14) and $V_{\text {FLT }}$ (pin 11) should be low leakage. In the application examples shown every 1.0 nA of leakage current will cause 0.1 mV error $\left(1.0 \times 10^{-9} \mathrm{~A} \times 100 \mathrm{k} \Omega=0.1 \mathrm{mV}\right)$. If the leakage current in both capacitors is exactly the same no error will result since the source impedances driving them are matched.


Figure 4. $31 / 2$-Digit DPM, +1.999 Volts Full Scale
LOSEOAV


Figure 5. $3 ½$-Digit DPM, $\pm 1.999$ Volts Full Scale


Figure 6. $3 ½$-Digit DVM, Four Decade, $\pm 0.2 \mathrm{~V}, \pm 2 \mathrm{~V}, \pm 20 \mathrm{~V}$ and $\pm 200 \mathrm{~V}$ Full Scale

## ADD3701 33/4 Digit DVM with Multiplexed 7-Segment Output

## General Description

The ADD3701 (MM74C936-1) monolithic DVM circuit is manufactured using standard complementary MOS (CMOS) technology. A pulse modulation analog-to-digital conversion technique is used and requires no external precision components. In addition, this technique allows the use of a reference voltage that is the same polarity as the input voltage.

One 5 V (TTL) power supply is required. Operating with an isolated supply allows the conversion of positive as well as negative voltages. The sign of the input voltage is automatically determined and output on the sign pin. If the power supply is not isolated, only one polarity of voltage may be converted.

The conversion rate is set by an internal oscillator. The frequency of the oscillator can be set by an external RC network or the oscillator can be driven from an external frequency source. When using the external RC network, a square wave output is available. It is important to note that great care has been taken to synchronize digit multiplexing with the $A / D$ conversion timing to eliminate noise due to power supply transients.

The ADD3701 has been designed to drive 7 -segment multiplexed LED displays directly with the aid of external digit buffers and segment resistors. Under condition of overrange, the overflow output will go high and the display will read +OFL or -OFL, depending on whether the input voltage is positive or negative. In addition to this, the most significant digit is blanked when zero.

A start conversion input and a conversion complete output are included.

## Features

- Operates from single 5 V supply
- Converts 0 to $\pm 3999$ counts
- Multiplexed 7-segment
- Drives segments directly
- No external precision components necessary
- Accuracy specified over temperature
- Medium speed $-400 \mathrm{~ms} /$ conversion
- Internal clock set with RC network or driven externally
- Overrange indicated by +OFL or -OFL display reading and OFLO output
- Analog inputs in applications shown can withstand $\pm 200$ Volts


## Applications

- Low cost digital power supply readouts
- Low cost digital multimeters
- Low cost digital panel meters
- Eliminate analog multiplexing by using remote $A / D$ converters
- Convert analog transducers (temperature, pressure, displacement, etc.) to digital transducers
- Indicators and displays requiring readout up to 3999 counts


## Connection Diagram



## Absolute Maximum Ratings

Voltage at Any Pin except Start Conversion $\quad-0.3 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{cc}}+0.3 \mathrm{~V}$

Voltage at Start Conversion -0.3 V to +15.0 V
Operating Temperature Range ( $\mathrm{T}_{A}$ )
Package Dissipation at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
Operating $V_{C C}$ Range
Absolute Maximum $V_{c c}$
Lead Temperature (Soldering, 10 seconds)
Storage Temperature Range
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

800 mW
4.5 V to 6.0 V
6.5 V
$300^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$

Electrical Characteristics ADD3701
$4.75 \mathrm{~V} \leqslant \mathrm{~V}_{\mathrm{CC}} \leqslant 5.25 \mathrm{~V},-40^{\circ} \mathrm{C} \leqslant \mathrm{T}_{\mathrm{A}} \leqslant+85^{\circ} \mathrm{C}$, unless otherwise specified.

|  | Parameter | Conditions | Min | Typ ${ }^{2}$ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage |  | $\mathrm{V}_{C C}-1.5$ |  |  | V |
| $\mathrm{V}_{\text {IN }}(0)$ | Logical "0" Input Voltage |  |  |  | 1.5 | V |
| $V_{\text {OUT }}(0)$ | Logical "0" Output Voltage (All Digital Outputs Except Digit Outputs) | $\mathrm{I}_{\mathrm{O}}=1.1 \mathrm{~mA}$ |  |  | 0.4 | V |
| $V_{\text {OUT(0) }}$ | Logical "0" Output Voltage (Digit Outputs) | $\mathrm{I}_{0}=0.7 \mathrm{~mA}$ |  |  | 0.4 | V |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage (All Segment Outputs) | $\begin{aligned} & \mathrm{I}_{\mathrm{O}}=50 \mathrm{~mA} @ \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{O}}=30 \mathrm{~mA} @ \mathrm{~T}_{\mathrm{J}}=100^{\circ} \mathrm{C} \end{aligned}$ | $\begin{aligned} & V_{c c}-1.6 \\ & V_{c c}-1.6 \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{cc}}-1.3 \\ & \mathrm{~V}_{\mathrm{cc}}-1.3 \end{aligned}$ |  | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $V_{\text {OUT(1) }}$ | Logical " 1 " Output Voltage (All Digital Outputs Except Segment Outputs) | $\mathrm{I}_{\mathrm{O}}=500 \mu \mathrm{~A}$ (Digit Outputs) <br> $\mathrm{I}_{\mathrm{O}}=360 \mu \mathrm{~A}$ (Conv. Complete, $+/-$, OFLO Outputs) | $\mathrm{V}_{\mathrm{cc}}-0.4$ |  |  | V |
| $I_{\text {SOURCE }}$ | Output Source Current (Digit Outputs) | $\mathrm{V}_{\text {OUT }}=1.0 \mathrm{~V}$ | 2.0 |  |  | $m A$ |
| $\operatorname{IN}(1)$ | Logical "1" Input Current (Start Conversion) | $V_{\text {IN }}=15 \mathrm{~V}$ |  |  | 1.0 | $\mu \mathrm{A}$ |
| $I_{\text {IN(0) }}$ | Logical " 0 " Input Current (Start Conversion) | $V_{\text {IN }}=0 \mathrm{~V}$Segments and Digits Open | -1.0 |  |  | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{cc}}$ | Supply Current |  |  | 0.5 | 10 | mA |
|  | Oscillator Frequency |  |  | 0.6/RC |  | kHz |
| $\mathrm{f}_{\mathrm{IN}}$ | Clock Frequency |  | 100 |  | 640 | . kHz |
| $\mathrm{f}_{\mathrm{C}}$ | Conversion Rate |  |  | $\mathrm{f}_{\mathrm{IN}} / 129,024$ |  | conv./sec |
| $\mathrm{f}_{\text {MUX }}$ | Digit Mux Rate |  |  | $\mathrm{f}_{\text {IN }} / 512$ |  | Hz |
| $t_{\text {blank }}$ | Inter Digit Blanking Time |  |  | 1/(32 $\mathrm{f}_{\text {MUX }}$ ) |  | seconds |
| tscPw | Start Conversion Pulse Width |  | 200 |  | DC | ns |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Range" they are not meant to imply that the devices should be operated at these limits. The table. of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: All typicals given for $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
Note 3: Full scale $=4000$ counts; therefore $0.025 \%$ of full scale $=1$ count and $0.05 \%$ of full scale $=2$ counts.
Note 4: For 2.000 Volts full scale, $1 \mathrm{mV}=2$ counts.

Electrical Characteristics ADD3701
$\mathrm{t}_{\mathrm{C}}=2.5$ conversions/second, $0^{\circ} \mathrm{C} \leqslant \mathrm{T}_{\mathrm{A}} \leqslant+70^{\circ} \mathrm{C}$, unless otherwise specified.

| Parameter | Conditions | Min | Typ ${ }^{2}$ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Non-Linearity of Output Reading | $V_{\text {IN }}=0-2 V$ Full Scale <br> $V_{\text {IN }}=0-200 \mathrm{mV}$ Full Scale | -0.05 | $\pm 0.025$ | +0.05 | \% full scale (Note 3) |
| Quantization Error |  | -1 |  | +0 | counts |
| Offset Error, $\mathrm{V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.5 | +1.5 | +3 | mV (Note 4) |
| Rollover Error |  | -0 |  | +0 | counts |
| Analog Input Current $\left(V_{I_{N}}, V_{I N^{-}}\right)$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | -5 | $\pm 1$ | +5 | $n A$ |

## Block Diagram



## Theory of Operation

A schematic for the analog loop is shown in figure 1. The output of SW1 is either at $\mathrm{V}_{\text {REF }}$ or zero volts, depending on the state of the $D$ flip-flop. If $Q$ is at a high level, $V_{\text {OUT }}=V_{\text {REF }}$ and if $Q$ is at a low level $V_{\text {OUT }}$ $=0 \mathrm{~V}$. This voltage is then applied to the low pass filter comprised of R1 and C 1 . The output of this filter, $\mathrm{V}_{\mathrm{FB}}$, is connected to the negative input of the comparator, where it is compared to the analog input voltage, $\mathrm{V}_{I N}$. The output of the comparator is connected to the D input of the $D$ flip-flop. Information is then transferred from the D input to the Q and Q outputs on the positive edge of clock. This loop forms an oscillator whose duty cycle is precisely related to the analog input voltage, $\mathrm{V}_{\text {IN }}$.

An example will demonstrate this relationship. Assume the input voltage is equal to 0.500 V . If the Q output of the $D$ flip-flop is high then $V_{\text {OUT }}$ will equal $V_{\text {REF }}$ $(2.000 \mathrm{~V})$ and $\mathrm{V}_{\mathrm{FB}}$ will charge toward 2 V with a time constant equal to $R_{1} C_{1}$. At some time $V_{F B}$ will exceed 0.500 V and the comparator output will switch to 0 V . At the next clock rising edge the Q output of the D flipflop will switch to ground, causing $\mathrm{V}_{\text {OUT }}$ to switch to 0 V . At this time $\mathrm{V}_{\mathrm{FB}}$ will start discharging toward 0 V with a time constant $R_{1} C_{1}$. When $V_{F B}$ is less than 0.5 V the comparator output will switch high. On the rising edge of the next clock the Q output of the D flip-flop will switch high and the process will repeat. There exists at the output of SW1 a square wave pulse train with positive amplitude $\mathrm{V}_{\text {REF }}$ and negative amplitude 0 V .

The $D C$ value of this pulse train is:

$$
V_{\text {OUT }}=V_{\text {REF }} \frac{t_{\text {ON }}}{t_{\text {ON }}+t_{\text {OFF }}}=V_{\text {REF }} \text { (duty cycle) }
$$

The lowpass filter will pass the DC value and then:

$$
V_{F B}=V_{\text {REF }} \text { (duty cycle) }
$$

Since the closed loop system will always force $V_{F B}$ to equal $\mathrm{V}_{\mathrm{IN}}$, we can then say that:

$$
V_{I N}=V_{F B}=V_{\text {REF }} \text { (duty cycle) }
$$

or

$$
\frac{V_{I N}}{V_{R E F}}=\text { (duty cycle) }
$$

The duty cycle is logically ANDed with the input frequency $f_{I N}$. The resultant frequency $f$ equals:

$$
f=(\text { duty cycle }) \times \text { (clock) }
$$

Frequency $f$ is accumulated by counter no. 1 for a time determined by counter no. 2. The count contained in counter no. 1 is then:

$$
\begin{aligned}
(\text { count }) & =\frac{f}{(\text { clock }) / \mathrm{N}}=\frac{(\text { duty cycle }) \times(\text { clock })}{(\text { clock }) / \mathrm{N}} \\
& =\frac{V_{I N}}{V_{\text {REF }}} \times \mathrm{N}
\end{aligned}
$$

For the ADD3701 $\mathrm{N}=4000$.

## Schematic Diagram



Figure 1. Analog Loop Schematic Pulse Modulation A/D Converter

## General Information

The timing diagram, shown in figure 2, gives operation for the free running mode. Free running operation is obtained by connecting the Start Conversion input to logic " 1 " ( $\mathrm{V}_{\mathrm{Cc}}$ ). In this mode the analog input is continuously converted and the display is updated at a rate equal to $129,024 \times 1 / \mathrm{f}_{\mathrm{IN}}$.
The rising edge of the Conversion Complete output indicates that new information has been transferred from the internal counter to the display latch. This information will remain in the display latch until the next low-to-high transition of the Conversion Complete output. A logic " 1 " will be maintained on the Conversion Complete output for a time equal to $128 \times 1 / \mathrm{f}_{\mathrm{IN}}$.

Figure 3 gives the operation using the Start Conversion input. It is important to note that the Start Conversion input and Conversion Complete output do not influence the actual analog-to-digital conversion in any way.

Internally the ADD3701 is always continuously converting the analog voltage present at its inputs. The Start Conversion input is used to control the transfer of information from the internal counter to the display latch.

An RS latch on the Start Conversion input allows a broad range of input pulse widths to be used on this signal. As shown in figure 3, the Conversion Complete output goes to a logic " 0 " on the rising edge of the Start Conversion pulse and goes to a logic " 1 " some time later when the new conversion is transferred from the internal counter to the display latch. Since the Start Conversion pulse can occur at any time during the conversion cycle, the amount of time from Start Conversion to Conversion Complete will vary. The maximum time is $129,024 \times 1 / \mathrm{f}_{\mathrm{IN}}$ and the minimum time is $512 \times 1 / \mathrm{fin}_{\mathrm{N}}$.

## Timing Waveforms



Figure 2. Conversion Cycle Timing Diagram for Free Running Operation


Figure 3. Conversion Cycle Timing Diagram Operating with Start Conversion Input

## Applications

## SYSTEM DESIGN CONSIDERATIONS

Perhaps the most important thing to consider when designing a system using the ADD3701 is power supply noise on the $\mathrm{V}_{\mathrm{Cc}}$ and ground lines. Because a single power supply is used and currents in the 300 mA range are being switched, good circuit layout techniques cannot be overemphasized. Great care has been exercised in the design of the ADD3701 to minimize these problems but poor printed circuit layout can negate these features.

Figures 4, 5, and 6 show schematics of DVM systems. An attempt has been made to show, on these schematics, the proper distribution for ground and $\mathrm{V}_{\mathrm{cc}}$. To help isolate digital and analog portions of the circuit, the analog $V_{C C}$ and ground have been separated from the digital $V_{C C}$ and ground. Care must be taken to eliminate high current from flowing in the analog $\mathrm{V}_{\mathrm{CC}}$ and ground wires. The most effective method of accomplishing this is to use a single ground point and a single $V_{c c}$ point where all wires are brought together. In addition to this the conductors must be of sufficient size to prevent significant voltage drops.

To prevent switching noise from causing jitter problems, a voltage regulator with good high frequency response is necessary. The LM309 and the LM340-5 voltage regulators all function well and are shown in figures 4, 5 , and 6 . Adding more filtering than is shown will in general increase the jitter rather than decrease it.

The most important characteristic of transients on the $\mathrm{V}_{\mathrm{Cc}}$ line is the duration of the transient and not its amplitude.

Figure 4 shows a DPM system which converts 0 to +3.999 counts operating from a non-isolated power supply. In this configuration the sign output could be + (logic " 1 ") or - (logic " 0 ") and it should be ignored. Higher voltages could be converted by placing a fixed divider on the input; lower voltages could be converted by placing a fixed divider on the feedback, as shown in figure 5 .

Figures 5 and 6 show systems operating with an isolated supply that will convert positive and negative inputs. 60 Hz common mode input becomes a problem in this configuration and a transformer with an electrostatic shield between primary and secondary windings is shown. The necessity for using a shielded transformer depends on the performance requirements and the actual application.

The filter capacitors connected to $\mathrm{V}_{\mathrm{FB}}$ (pin 14) and $\mathrm{V}_{\text {FLT }}$ (pin 11) should be low leakage. In the application examples shown every 1.0 nA of leakage current will cause 0.1 mV error $\left(1.0 \times 10^{-9} \mathrm{~A} \times 100 \mathrm{k} \Omega=0.1 \mathrm{mV}\right)$. If the leakage current in both capacitors is exactly the same no error will result since the source impedances driving them are matched.


Figure 4. 33/4-Digit DPM, +3.999 Count Full Scale


Figure 5. $33 / 4$-Digit DPM, $\pm 3.999$ Counts Full Scale


Figure 6. $33 / 4$-Digit DVM, Four Decade, $\pm 0.4 \mathrm{~V}, \pm 4 \mathrm{~V}, \pm 40 \mathrm{~V}$, and $\pm 400 \mathrm{~V}$ Full Scale


Figure 7. ADD3701 Driving Liquid Crystal Display

## MM54C905/MM74C905 12-Bit Successive Approximation Register

## General Description

The MM54C905/MM74C905 CMOS 12-bit successive approximation register contains all the digit control and storage necessary for successive approximation analogto digital conversion. Because of the unique capability of CMOS to switch to each supply rail without any offset voltage, it can also be used in digital systems as the control and storage element in repetitive routines.

## Features

- Wide supply voltage range 3.0 V to 15 V

Guaranteed noise margin $10 . \mathrm{V}$
■ High noise immunity $0.45 \mathrm{~V}_{\mathrm{CC}}$ typ.

- Low power TTL fan out of 2 compatibility driving 74L
- Provision for register extension or truncation
- Operates in START/STOP or continuous conversation mode
- Drive ladder switches directly. For 10 bits or less with $50 \mathrm{k} / 100 \mathrm{k}$ R/2R ladder network


## ADC0801, ADC0802, ADC0803, ADC0804, ADC0805 8-Bit $\mu$ P Compatible A/D Converters

## General Description

The ADC0801, ADC0802, ADC0803, ADC0804 and ADC0805 are CMOS 8-bit successive approximation A/D converters which use a differential potentiometric ladder-similar to the 256 R products. These converters are designed to allow operation with the 8080A control bus, and TRI-STATE ${ }^{\circledR}$ output latches directly drive the data bus. These A/Ds appear like memory locations or I/O ports to the microprocessor and no interfacing logic is needed.

A new differential analog voltage input allows increasing the common-mode rejection and offsetting the analog zero input voltage value. In addition, the voltage reference input can be adjusted to allow encoding any smaller analog voltage span to the full 8 bits of resolution.

## Features

- Compatible with $8080 \mu \mathrm{P}$ derivatives-no interfacing logic needed
- Easy interface to all microprocessors, or operates "stand alone"
- Differential analog voltage inputs
- Logic inputs and outputs meet both MOS and $T^{2} \mathrm{~L}$ voltage level specifications
- Works with 2.5 V (LM336) voltage reference
- On-chip clock generator
- 0 V to 5 V analog input voltage range with single 5 V supply
- No zero adjust required
- $0.3^{\prime \prime}$ standard width 20-pin DIP package


## Key Specifications

- Resolution

8 bits

- Total error $\pm 1 / 4$ LSB,$\pm 1 / 2$ LSB and $\pm 1$ LSB
- Conversion time $100 \mu \mathrm{~s}$
- Access time 135 ns
- Single supply 5 VDC
- Operates ratiometrically or with $5 \mathrm{~V}_{\mathrm{DC}}, 2.5 \mathrm{~V}_{\mathrm{DC}}$, or analog span adjusted voltage reference



## Absolute Maximum Ratings (Notes 1 and 2)

## Operating Ratings (Notes 1 and 2)

```
Supply Voltage (VCC) (Note 3)
Voltage
    Logic Control Inputs
                            -0.3V to +18V
    At Other Input and Outputs
    -0.3V to (VCC}+0.3\textrm{V}
Storage Temperature Range
Package Dissipation at TA}=2\mp@subsup{5}{}{\circ}\textrm{C
Lead Temperature (Soldering, 10 seconds)
6.5V
-65 C to +150 %
875 mW
```

Temperature Range (Note 1)
ADC0801/02/03LD
$T_{M I N} \leq T_{A} \leq T_{M A X}$
$-55^{\circ} \mathrm{C} \leq T_{A} \leq+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C} \leq \mathrm{T}_{A} \leq+85^{\circ} \mathrm{C}$
ADC0801/02/03/04LCD
ADC0801/02/03/05LCN
$-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$
$0^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+70^{\circ} \mathrm{C}$
ADC0804LCN
$0^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+70^{\circ} \mathrm{C}$

## Electrical Characteristics

The following specifications apply for $V_{C C}=5 V_{D C}, T_{M I N} \leq T_{A} \leq T_{M A X}$ and $f_{C L K}=640 \mathrm{kHz}$ unless otherwise specified.

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ADC0801: |  |  |  |  |  |
| Total Adjusted Error (Note 8) | With Full-Scale Adj. (See Section 2.5.2) |  |  | $\pm 1 / 4$ | LSB |
| ADC0802: |  |  |  |  |  |
| Total Unadjusted Error (Note 8) | $\mathrm{V}_{\mathrm{REF}} / 2=2.500 \mathrm{~V} \mathrm{DC}$ <br> (RSOURCE $\leq 20 \Omega$ ) | . |  | $\pm 1 / 2$ | LSB |
| ADC0803: |  |  |  |  |  |
| Total Adjusted Error (Note 8) | With Full-Scale Adj. (See Section 2.5.2) |  |  | $\pm 1 / 2$ | LSB |
| ADC0804: |  |  |  |  |  |
| Total Unadjusted Error (Note 8) | $\mathrm{V}_{\text {REF } / 2}=2.500 \mathrm{~V}_{\mathrm{DC}}$ <br> (RSOURCE $\leq 20 \Omega$ ) |  |  | $\pm 1$ | LSB |
| ADC0805: <br> Total Unadjusted Error | $V_{\text {REF }} / 2$ - NC <br> (RSOURCE $\leq 20 \Omega$ ) |  |  | $\pm 1$ | LSB |
| Total Unadjusted Error | (RSOURCE $\leq 20 \Omega$ ) |  |  |  |  |
| $V_{\text {REF } / 2 ~ I n p u t ~ R e s i s t a n c e ~(~}^{\text {Pin } 9)}$ | ADC0801/02/03/05 | 2.5 | 8.0 |  | - $k \Omega$ |
|  | ADC0804 (Note 9) | 1.0 | 1.3 |  | $k \Omega$ |
| Analog Input Voltage Range | (Note 4) V $(+)$ or $\mathrm{V}(-)$ | Gnd-0.05 |  | $\mathrm{V}_{\mathrm{CC}}+0.05$ | VDC |
| DC Common-Mode Rejection | Over Analog Input Voltage Range |  | $\pm 1 / 16$ | $\pm 1 / 8$ | LSB |
| Power Supply Sensitivity | $V_{C C}=5 V_{D C} \pm 10 \% \text { Over }$ <br> Allowed $V_{\text {IN }}(+)$ and $V_{\text {IN }}(-)$ <br> Voltage Range (Note 4) |  | $\pm 1 / 16$ | $\pm 1 / 8$ | LSB |

## AC Electrical Characteristics

The following specifications apply for $\mathrm{V}_{C C}=5 \mathrm{~V}_{D C}$ and $T_{A}=25^{\circ} \mathrm{C}$ unless otherwise specified.


## Electrical Characteristics

The following specifications apply for $V_{C C}=5 V_{D C}$ and $T_{M I N} \leq T_{A} \leq T_{M A X}$, unless otherwise specified.

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| CONTROL INPUTS [Note: CLK IN (Pin 4) is the input of a Schmitt trigger circuit and is therefore specified separately] |  |  |  |  |  |
| VIN (1) Logical " 1 " Input Voltage (Except Pin 4 CLK IN) | $V_{C C}=5.25 V_{D C}$ | 2.0 |  | 15 | VDC |
| VIN (0) Logical "0" Input Voltage (Except Pin 4 CLK IN) | $V_{C C}=4.75 V_{D C}$ |  |  | 0.8 | VDC |
| IIN (1) Logical "1" Input Current (All Inputs) | $V_{I N}=5 V_{D C}$ |  | 0.005 | 1 | $\mu A D C$ |
| IIN (0) Logical "0" Input Current (All Inputs) | $V_{\text {IN }}=0 V_{\text {DC }}$ | -1 | -0.005 |  | $\mu \mathrm{ADC}$ |
| CLOCK IN AND CLOCK R |  |  |  |  |  |
| $\begin{array}{ll} \mathrm{V}_{\mathrm{T}^{+}} & \text {CLK IN (Pin 4) Positive Going } \\ & \text { Threshold Voltage } \end{array}$ |  | 2.7 | 3.1 | 3.5 | VDC |
| $V_{T^{-}} \quad$ CLK IN (Pin 4) Negative Going Threshold Voltage |  | 1.5 | 1.8 | 2.1 | $V_{\text {DC }}$ |
| $\begin{array}{ll} V_{H} & \text { CLK IN (Pin 4) Hysteresis } \\ & \left(V_{T^{+}}\right)-\left(V_{T}-1\right. \end{array}$ |  | 0.6 | 1.3 | 2.0 | $V_{\text {DC }}$ |
| VOUT (0) Logical "0" CLK R Output Voltage | $\begin{aligned} & I_{O}=360 \mu \mathrm{~A} \\ & V_{C C}=4.75 V_{D C} \end{aligned}$ |  |  | 0.4 | $V_{D C}$ |
| VOUT (1) Logical " 1 " CLK R Output Voltage | $\begin{aligned} & I_{0}=-360 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}_{\mathrm{DC}} \end{aligned}$ | 2.4 |  |  | $V_{\text {DC }}$ |
| DATA OUTPUTS AND INTR |  |  |  |  |  |
| VOUT(0) Logical "0" Output Voltage Data Outputs <br> INTR Output | $\begin{aligned} & \mathrm{I}_{\mathrm{OUT}}=1.6 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{VDC} \\ & \mathrm{I}_{\mathrm{DUT}}=1.0 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{VDC} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & V_{D C} \\ & V_{D C} \end{aligned}$ |
| VOUT (1) Logical " 1 " Output Voltage | $\mathrm{I}^{\prime} \mathrm{O}=-360 \mu \mathrm{~A}, \mathrm{~V}_{C C}=4.75 \mathrm{~V}_{\text {DC }}$ | 2.4 |  |  | VDC |
| VOUT (1) Logical "1" Output Voltage | $\mathrm{I}_{\mathrm{O}}=-10 \mu \mathrm{~A}, \mathrm{~V}_{C C}=4.75 \mathrm{~V}_{\mathrm{DC}}$ | 4.5 |  |  | $V_{D C}$ |
| IOUT TRI-STATE Disabled Output Leakage (All Data Buffers) | $\begin{aligned} & V_{\text {OUT }}=0 V_{D C} \\ & V_{\text {OUT }}=5 V_{D C} \end{aligned}$ | -3 |  | 3 | $\mu A D C$ $\mu A D C$ |
| ISOURCE | VOUT Short to Gnd, $\mathrm{TA}_{\text {A }}=25^{\circ} \mathrm{C}$ | 4.5 | 6 |  | $m A D C$ |
| ISINK | $V_{\text {OUT }}$ Short to $V_{\text {CC, }}, T_{A}=25^{\circ} \mathrm{C}$ | 9.0 | 16 |  | $m A D C$ |
| POWER SUPPLY |  |  |  |  |  |
| ICC Supply Current (Includes <br> Ladder Current) | $\begin{aligned} & \mathrm{f}_{\mathrm{CLK}}=640 \mathrm{kHz}, \\ & \mathrm{~V}_{\mathrm{REF} / 2}=\mathrm{NC}, \mathrm{~T}_{A}=25^{\circ} \mathrm{C} \\ & \text { and } \overline{\mathrm{CS}}=" 1 " \\ & \mathrm{ADC0801/02/03} \\ & \text { ADC0804 (Note } 9 \text { ) } \end{aligned}$ | , | $\begin{aligned} & 1.1 \\ & 1.9 \\ & \hline \end{aligned}$ | $\begin{aligned} & 1.8 \\ & 2.5 \end{aligned}$ | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |

Note 1: Absolute maximum ratings are those values beyond which the life of the device may be impaired.
Note 2: All voltages are measured with respect to Gnd, unless otherwise specified. The separate A Gnd point should always be wired to the D Gnd.
Note 3: A zener diode exists, internally, from $V_{C C}$ to $G$ nd and has a typical breakdown voltage of $7 \mathrm{~V}_{\mathrm{DC}}$.
Note 4: For $V_{I N}(-) \geq V_{I N}(+)$ the digital output code will be 00000000 . Two on-chip diodes are tied to each analog input (see block diagram) which will forward conduct for analog input voltages one diode drop below ground or one diode drop greater than the $\mathrm{V}_{\mathrm{CC}}$ supply. Be careful, during testing at low $V_{\text {CC }}$ levels ( 4.5 V ), as high level analog inputs ( 5 V ) can cause this input diode to conduct-especially at elevated temperatures, and cause errors for analog inputs near full-scale. The spec allows 50 mV forward bias of either diode. This means that as long as the analog $V$ IN does not exceed the supply voltage by more than 50 mV , the output code will be correct. To achieve an absolute $0 V_{D C}$ to $5 V_{D C}$ input voltage range will therefore require a minimum supply voltage of $4.950 \mathrm{~V}_{\mathrm{DC}}$ over temperature variations, initial tolerance and loading.
Note 5: With $V_{C C}=6 \mathrm{~V}$, the digital logic interfaces are no longer TTL compatible.
Note 6: With an asynchronous start pulse, up to 8 clock periods may be required before the internal clock phases are proper to start the conversion . process. The start request is internally latched, see Figure 2 and section 2.0.
Note 7: The $\overline{C S}$ input is assumed to bracket the $\overline{W R}$ strobe input and therefore timing is dependent on the $\overline{W R}$ pulse width. An arbitrarily wide pulse width will hold the converter in a reset mode and the start of conversion is initiated by the low to high transition of the WR pulse (see timing diagrams).
Note 8: None of these A/Ds requires a zero adjust (see section 2.5.1). To obtain zero code at other analog input voltages see section 2.5 and Figure 5.
Note 9: For ADC0804LCD typical value of $V_{R E F} / 2$ input resistance is $8 \mathrm{k} \Omega$ and of $I_{C C}$ is 1.1 mA .

Logic Input Threshold Voltage vs. Supply Voltage



Output Current vs Temperature


Delay From Falling Edge of $\overline{R D}$ to Output Data Valid vs. Load Capacitance


Full-Scale Error vs fCLK


Power Supply Current vs Temperature (Note 9)


CLK IN Schmitt Trip Levels vs. Supply Voltage


Effect of Unadjusted Offset Error vs. $V_{\text {REF }} / 2$ Voltage


Linearity Error at Low VREF/2 Voltages


## TRI-STATE ${ }^{\circledR}$ Test Circuits and Waveforms



Timing Diagrams


Output Enable and Reset INTR


Note: All timing is measured from the 50\% voltage points.

Typical Applications (Continued)


Ratiometric with Full-Scale Adjust
 see section 2.3.2 Input Bypass Capacitors.

Absolute with a 2.500 V Reference


Zero-Shift and Span Adjust: $\mathbf{2 V} \leq \mathrm{V}_{\text {IN }} \leq 5 \mathrm{~V}$


Absolute with a 5V Reference


Zero-Shift and Span Adjust: $\mathbf{0 V} \leq \mathrm{V}_{\mathbf{I N}} \leq \mathbf{3 V}$


Typical Applications (Continued)

Directly Converting a Low-Level Signal


A $\mu \mathrm{P}$ Interfaced Comparator


$$
\begin{aligned}
\text { For: } & V_{\text {IN }}(+)>V_{\text {IN }}(-) \\
& \text { Output }^{\left(-F_{\text {F }}^{\text {HEX }}\right.} \\
\text { For: } & V_{\text {IN }}(+)<V_{\text {IN }}(-) \\
\text { Output } & =00_{\text {HEX }}
\end{aligned}
$$

1 mV Resolution with $\mu \mathrm{P}$ Controlled Range
$V_{\text {REF }} / 2=128 \mathrm{mV}$
$1 \mathrm{LSB}=1 \mathrm{mV}$
$V_{D A C} \leq V_{I N} \leq\left(V_{D A C}+256 \mathrm{mV}\right)$


Digitizing a Current Flow


Typical Applications (Continued)
Self-Clocking Multiple A/Ds


External Clocking

$100 \mathrm{kHz} \leq \mathrm{f}^{\mathrm{C}} \mathrm{CLK} \leq 800 \mathrm{kHz}$

Self-Clocking in Free-Running Mode


* After power-up, a momentary grounding of the WR input is needed to guarantee operation.
$\mu \mathrm{P}$ Interface for Free-Running $\mathrm{A} / \mathrm{D}$


Operating with "Automotive" Ratiometric Transducers


Ratiometric with $V_{R E F} / 2$ Forced


Typical Applications (Continued)
$\mu$ P Compatible Differential-Input Comparator with Pre-Set VOS (with or without Hysteresis)


DB7 $=$ " 1 " for $V_{\text {IN }}(+)>V_{\text {IN }}(-)+2\left(V_{\text {REF }} / 2\right)$
Omit circuitry within the dotted area if hysteresis is not needed

## Handling $\pm 10 \mathrm{~V}$ Analog Inputs

Low-Cost, $\mu$ P Interfaced, Temperature-to-Digital Converter

*Beckman Instruments \#694-3-R10K resistor array
$\mu \mathrm{P}$ Interfaced Temperature-to-Digital Converter


## 

Typical Applications (Continued)

Handling $\pm 5 \mathrm{~V}$ Analog Inputs
 $\mu \mathrm{P}$ Interfaced Comparator with Hysteresis


Analog Self-Test for a System


Read-Only Interface


Protecting the Input


A Low-Cost, 3-Decade Logarithmic Converter


* LM389 transistors
$A, B, C, D=L M 324 A$ quad op amp

Typical Applications (Continued)

## 3-Decade Logarithmic A/D Converter



Noise Filtering the Analog Input is used


Multiplexing Differential Inputs


Output Buffers with A/D Data Enabled

*A/D output data is updated 1 CLK period prior to assertion of INTR

Increasing Bus Drive and/or Reducing Time on Bus

*Allows output data to set-up at falling edge of $\overline{C S}$


Note 1: Oversample whenever possible [keep fs $>2 f(-60)$ ] to eliminate input frequency folding (aliasing) and to allow for the skirt response of the filter.
Note 2: Consider the amplitude errors which are introduced within the passband of the filter.

70\% Power Savings by. Clock Gating


Power Savings by A/D and $V_{\text {REF }}$ Shutdown

*Use ADC0801, 02 or 03 for lowest power consumption.
Note: Logic inputs can be driven to $V_{C C}$ with $A / D$ supply at zero volts.
Buffer prevents data bus from overdriving outputs of $A / D$ when in shutdown mode.

A perfect A/D transfer characteristic (staircase waveform) is shown in Figure 1a. The horizontal scale is analog input voltage and the particular points labeled are in steps of 1 LSB ( 19.53 mV with 2.5 V tied to the $\mathrm{V}_{\text {REF }} / 2$ pin). The digital output codes which correspond to these inputs are shown as $\mathrm{D}-1, \mathrm{D}$, and $\mathrm{D}+1$. For the perfect $A / D$, not only will center-value ( $A-1, A$, $A+1$, . . .) analog inputs produce the correct output digital codes, but also each riser (the transitions between adjacent output codes) will be located $\pm 1 / 2$ LSB away from each center-value. As shown, the risers are ideal and have no width. Correct digital output codes will be provided for a range of analog input voltages which extend $\pm 1 / 2$ LSB from the ideal center-values. Each tread (the range of analog input voltage which provides the same digital output code) is therefore 1 LSB wide.

Figure 16 shows a worst case error plot for the ADC0801. All center-valued inputs are guaranteed to produce the correct output codes and the adjacent risers are guaranteed to be no closer to the center-value points than

Transfer Function
$\pm 1 / 4$ LSB. In other words, if we apply an analog input equal to the center-value $\pm 1 / 4$ LSB, we guarantee that the $A / D$ will produce the correct digital code. The maximum range of the position of the code transition is indicated by the horizontal arrow and it is guaranteed to be no more than $1 / 2$ LSB.
The error curve of Figure $1 c$ shows a worst case error plot for the ADC0802. Here we guarantee that if we apply an analog input equal to the LSB analog voltage center-value the $A / D$ will produce the correct digital code.

Next to each transfer function is shown the corresponding error plot. Many people may be more familiar with error plots than transfer functions. The analog input voltage to the $A / D$ is provided by either a linear ramp or by the discrete output steps of a high resolution DAC. Notice that the error is continuously displayed and includes the quantization uncertainty of the $A / D$. For example the error at point 1 of Figure $1 a$ is $+1 / 2$ LSB because the digital code appeared $1 / 2$ LSB in advance of the center-value of the tread. The error plots always have a constant negative slope and the abrupt upside steps are always 1 LSB in magnitude.

a) Accuracy $= \pm 0$ LSB A Perfect $A / D$


Transfer Function


Transfer Function


Error Plot

b) Accuracy $= \pm 1 / 4$ LSB

### 2.0 FUNCTIONAL DESCRIPTION

The ADC0801 series contains a circuit equivalent of the 256R network. Analog switches are sequenced by successive approximation logic to match the analog difference input voltage $\left[\mathrm{V}_{1 \mathrm{~N}}(+)-\mathrm{V}_{\mathrm{IN}}(-)\right]$ to a corresponding tap on the R network. The most significant bit is tested first and after 8 comparisons ( 64 clock cycles) a digital 8 -bit binary code (1111 $1111=$ fullscale) is transferred to an output latch and then an interrupt is asserted (INTR makes a high-to-low transition). A conversion in process can be interrupted by issuing a second start command. The device may be operated in the free-running mode by connecting INTR to the $\overline{W R}$ input with $\overline{\mathrm{CS}}=0$. To insure start-up under all possible conditions, an external $\overline{W R}$ pulse is required during the first power-up cycle.

On the high-to-low transition of the $\overline{W R}$ input the internal SAR latches and the shift register stages are reset. As long as the $\overline{\mathrm{CS}}$ input and $\overline{\mathrm{WR}}$ input remain low, the $A / D$ will remain in a reset state. Conversion will start from 1 to 8 clock periods after at least one of these inputs makes a low-to-high transition.

A functional diagram of the A/D converter is shown in Figure 2. All of the package pinouts are shown and the major logic control paths are drawn in heavier weight lines.

The converter is started by having $\overline{\mathrm{CS}}$ and $\overline{\mathrm{WR}}$ simultaneously low. This sets the start flip-flop (F/F) and the resulting " 1 " level resets the 8 -bit shift register, resets the Interrupt (INTR) F/F and inputs a " 1 " to the D flop, F/F1, which is at the input end of the 8 -bit shift register. Internal clock signals then transfer this " 1 " to the Q output of $\mathrm{F} / \mathrm{F} 1$. The AND gate, G1, combines this " 1 " output with a clock signal to provide a reset signal to the start $\mathrm{F} / \mathrm{F}$. If the set signal is no longer present (either $\overline{W R}$ or $\overline{C S}$ is a " 1 ") the start $F / F$ is reset and the 8 -bit shift register then can have the " 1 " clocked in, which starts the conversion process. If the set signal were to still be present, this reset pulse would have no effect (both outputs of the start F/F would momentarily be at a " 1 " level) and the 8 -bit shift register would continue to be held in the reset mode. This logic therefore allows for wide $\overline{\mathrm{CS}}$ and $\overline{\mathrm{WR}}$ signals and the converter will start after at least one of these signals returns high and the internal clocks again provide a reset signal for the start F/F.


Note 1: $\overline{\mathrm{CS}}$ shown twice for clarity.
Note 2: SAR = Successive Approximation Register.
FIGURE 2. Block Diagram .

After the " 1 " is clocked through the 8 -bit shift register (which completes the SAR search) it appears as the input to the D-type latch, LATCH 1. As-soon as this " 1 " is output from the shift register, the AND gate, G2, causes the new digital word to transfer to the TRI-STATE output latches. When LATCH 1 is subsequently enabled, the Q output makes a high-to-low transition which causes the INTR F/F to set. An inverting buffer then supplies the INTR output signal.

Note that this $\overline{\text { SET }}$ control of the INTR F/F remains low for 8 of the external clock periods (as the internal clocks run at $1 / 8$ of the frequency of the external clock). If the data output is continuously enabled ( $\overline{\mathrm{CS}}$ and $\overline{\mathrm{RD}}$ both held low), the $\overline{\mathrm{NTR}}$ output will still signal the end of conversion (by a high-to-low transition), because the $\overline{\mathrm{SET}}$ input can control the Q output of the INTR F/F even though the RESET input is constantly at a " 1 " level in this operating mode. This $\overline{\text { NTR }}$ output will therefore stay low for the duration of the $\overline{\mathrm{SET}}$ signal; which is 8 periods of the external clock frequency (assuming the $A / D$ is not started during this interval).

When operating in the free-running or continuous conversion mode (INTR pin tied to $\overline{W R}$ and $\overline{\mathrm{CS}}$ wired low-see also section 2.8), the START F/F is SET by the high-to-low transition of the $\overline{\text { INTR }}$ signal. This resets the SHIFT REGISTER which causes the input to the D-type latch, LATCH 1, to go low. As the latch enable input is still present, the $\overline{\mathrm{Q}}$ output will go high, which then allows the INTR F/F to be RESET. This reduces the width of the resulting INTR output pulse to only a few propagation delays (approximately 300 ns ).

When data is to be read, the combination of both $\overline{\mathrm{CS}}$ and $\overline{\mathrm{RD}}$ being low will cause the INTR F/F to be reset and the TRI-STATE output latches will be enabled to provide the 8 -bit digital outputs.

### 2.1 Digital Control Inputs

The digital control inputs ( $\overline{\mathrm{CS}}, \overline{\mathrm{RD}}$, and $\overline{\mathrm{WR}}$ ) meet standard $\mathrm{T}^{2} \mathrm{~L}$ logic voltage levels. These signals have been renamed when compared to the standard A/D Start and Output Enable labels. In addition, these inputs are active low to allow an easy interface to microprocessor control busses. For non-microprocessor based applications, the $\overline{\mathrm{CS}}$ input (pin 1) can be grounded and the standard A/D Start function is obtained by an active low pulse applied at the $\overline{W R}$ input ( $p$ in 3) and the Output Enable function is caused by an active low pulse at the $\overline{\mathrm{RD}}$ input (pin 2).

### 2.2 Analog Differential Voltage Inputs and Common-Mode Rejection

This A/D has additional applications flexibility due to the analog differential voltage input. The $\left.\mathrm{V}_{\text {IN }} \mathrm{N}^{-}\right)$input (pin 7) can be used to automatically subtract a fixed voltage value from the input reading (tare correction). This is also useful in $4 \mathrm{~mA}-20 \mathrm{~mA}$ current loop conversion. In addition, common-mode noise can be reduced by use of the differential input.

The time interval between sampling $V_{I N}(+)$ and $V_{I N}(-)$ is $4-1 / 2$ clock periods. The maximum error voltage due
to this slight time difference between the input voltage samples is given by:

$$
\Delta V_{e}(\mathrm{MAX})=\left(\mathrm{V}_{\mathrm{P}}\right)\left(2 \pi \mathrm{f}_{\mathrm{cm}}\right)\left(\frac{4.5}{\mathrm{fCLK}}\right)
$$

where:
$\Delta V_{e}$ is the error voltage due to sampling delay
$V_{P}$ is the peak value of the common-mode voltage
$\mathrm{f}_{\mathrm{cm}}$ is the common-mode frequency
As an example, to keep this error to $1 / 4 \mathrm{LSB}(\sim 5 \mathrm{mV})$ when operating with a 60 Hz common-mode frequency, $\mathrm{f}_{\mathrm{cm}}$, and using a 640 kHz A/D clock, ${ }^{\mathrm{f}} \mathrm{CLK}$, would allow a peak value of the common-mode voltage, Vp , which is given by:

$$
V_{P}=\frac{\left[\Delta V_{\mathrm{e}(\mathrm{MAX})(\mathrm{fCLK})]}\right.}{\left(2 \pi \mathrm{f}_{\mathrm{cm}}\right)(4.5)}
$$

or

$$
V_{P}=\frac{\left(5 \times 10^{-3}\right)\left(640 \times 10^{3}\right)}{(6.28)(60)(4.5)}
$$

which gives

$$
V_{P} \cong 1.9 \mathrm{~V}
$$

The allowed range of analog input voltages usually places more severe restrictions on input common-mode noise levels.

An analog input voltage with a reduced span and a relatively large zero offset can be easily handled by making use of the differential input (see section 2.4 Reference Voltage).

### 2.3 Analog Inputs

### 2.3.1 Input Current

## Normal Mode

Due to the internal switching action, displacement currents will flow at the analog inputs. This is due to onchip stray capacitance to ground as shown in Figure 3.


FIGURE 3. Analog Input Impedance

The voltage on this capacitance is switched and will result in currents entering the $\mathrm{V}_{1 N}(+)$ input pin and leaving the $\operatorname{VIN}(-)$ input which will depend on the analog differential input voltage levels. These current transients occur at the leading edge of the internal clocks. They rapidly decay and do not cause errors as the on-chip comparator is strobed at the end of the clock period.

## Fault Mode

If the voltage source which is applied to the $\mathrm{V}_{\text {IN }}(+)$ pin exceeds the allowed operating range of $\mathrm{V}_{\mathrm{CC}}+$ 50 mV , large input currents can flow through a parasitic diode to the $V_{C C}$ pin. If these currents could exceed the 1 mA max allowed spec, an external diode (1N914) should be added to bypass this current to the $V_{C C}$ pin (with the current bypassed with this diode, the voltage at the $\mathrm{V}_{1 \mathrm{~N}}(+)$ pin can exceed the $\mathrm{V}_{\mathrm{CC}}$ voltage by the forward voltage of this diode).

### 2.3.2 Input Bypass Capacitors

Bypass capacitors at the inputs will average these charges and cause a DC current to flow through the output resistances of the analog signal sources. This charge pumping action is worse for continuous conversions with the $\mathrm{V}_{1 \mathrm{~N}^{(+)}}{ }^{+}$input voltage at full-scale. For continuous conversions with a 640 kHz clock frequency with the $V_{1 N^{(+)}}{ }^{+}$input at 5 V , this DC current is at a maximum of approximately $5 \mu \mathrm{~A}$. Therefore, bypass capacitors should not be used at the analog inputs or the $V_{R E F} / 2$ pin for high resistance sources ( $>1 \mathrm{k} \Omega$ ). If input bypass capacitors are necessary for noise filtering and high source resistance is desirable to minimize capacitor size, the detrimental effects of the voltage drop across this input resistance, which is due to the average value of the input current, can be eliminated with a full-scale adjustment while the given source resistor and input bypass capacitor are both in place. This is possible because the average value of the input current is a precise linear function of the differential input voltage.

### 2.3.3 Input Source Resistance

Large values of source resistance where an input bypass capacitor is not used, will not cause errors as the input currents settle out prior to the comparison time. If a low pass filter is required in the system, use a low valued series resistor $(\leq 1 \mathrm{k} \Omega)$ for a passive $R C$ section or add an op amp RC active low pass filter. For low source resistance applications, ( $\leq 1 \mathrm{k} \Omega$ ), a $0.1 \mu \mathrm{~F}$ bypass capacitor at the inputs will prevent pickup due to series lead inductance of a long wire. A $100 \Omega$ series resistor can be used to isolate this capacitor-both the R and C are placed outside the feedback loop-from the output of an op amp, if used.

### 2.3.4 Noise

The leads to the analog inputs (pins 6 and 7) should be kept as short as possible to minimize input noise coupling. Both noise and undesired digital clock coupling to these inputs can cause system errors. The source resistance for these inputs should, in general, be kept below $5 \mathrm{k} \Omega$. Larger values of source resistance can cause undesired system noise pickup. Input bypass capacitors, placed from the analog inputs to ground, will eliminate
system noise pickup but can create analog scale errors as these capacitors will average the transient input switching currents of the A/D (see section 2.3.1). This scale error depends on both a large source resistance and the use of an input bypass capacitor. This error can be eliminated by doing a full-scale adjustment of the A/D (adjust $\mathrm{V}_{\mathrm{REF}} / 2$ for a proper full-scale reading-see section 2.5.2 on Full-Scale Adjustment) with the source resistance and input bypass capacitor in place.

### 2.4 Reference Voltage

### 2.4.1 Span Adjust

For maximum applications flexibility, these $A / D s$ have been designed to accommodate a $5 \mathrm{~V}_{\mathrm{DC}}, 2.5 \mathrm{~V}_{\mathrm{DC}}$ or an adjusted voltage reference. This has been achieved in the design of the IC as shown in Figure 4.


FIGURE 4. The VREFERENCE Design on the IC

Notice that the reference voltage for the IC is either $1 / 2$ of the voltage which is applied to the $\mathrm{V}_{\mathrm{CC}}$ supply pin, or is equal to the voltage which is externally forced at the $V_{R E F} / 2$ pin. This allows for a ratiometric voltage reference using the $V_{C C}$ supply, a $5 V_{D C}$ reference voltage can be used for the $V_{C C}$ supply or a voltage less than $2.5 V_{D C}$ can be applied to the $V_{\text {REF }} / 2$ input for increased application flexibility. The internal gain to the $V_{\text {REF }} / 2$ input is 2 .

An example of the use of an adjusted reference voltage is to accommodate a reduced span-or dynamic voltage range of the analog input voltage. If the analog input voltage were to range from $0.5 \mathrm{~V} D C$ to $3.5 \mathrm{~V} D C$, instead of 0 V to 5 VDC , the span would be 3 V as shown in Figure 5. With $0.5 \mathrm{~V}_{\mathrm{DC}}$ applied to the $\mathrm{V}_{I N}(-)$ pin to absorb the offset, the reference voltage can be made equal to $1 / 2$ of the 3 V span or 1.5 V DC. The $\mathrm{A} / \mathrm{D}$ now will encode the $\mathrm{V}_{1 \mathrm{~N}} \mathrm{~S}^{+}$) signal from 0.5 V to 3.5 V with the 0.5 V input corresponding to zero and the $3.5 \mathrm{~V} D C$ input corresponding to full-scale. The full 8 bits of resolution are therefore applied over this reduced analog input voltage range.


FIGURE 5. Adapting the A/D Analog Input Voltages to Match an Arbitrary Input Signal Range

### 2.4.2 Reference Accuracy Requirements

The converter can be operated in a ratiometric mode or an absolute mode. In ratiometric converter applications, the magnitude of the reference voltage is a factor in both the output of the source transducer and the output of the $A / D$ converter and therefore cancels out in the final digital output code. In absolute conversion applications, both the initial value and the temperature stability of the reference voltage are important accuracy factors in the operation of the $A / D$ converter. For $V_{R E F} / 2$ voltages of $2.5 V_{D C}$ nominal value, initial errors of $\pm 10 \mathrm{~m} V_{D C}$ will cause conversion errors of $\pm 1$ LSB due to the gain of 2 of the $V_{\text {REF }} / 2$ input. In reduced span applications, the initial value and the stability of the $V_{\text {REF }} / 2$ input voltage become even more important. For example, if the span is reduced to 2.5 V , the analog input LSB voltage value is correspondingly reduced from 20 mV ( 5 V span) to 10 mV and 1 LSB at the $\mathrm{V}_{\text {REF }} / 2$ input becomes 5 mV . As can be seen, this reduces the allowed initial tolerance of the reference voltage and requires correspondingly less absolute change with temperature variations. Note that spans smaller than 2.5 V place even tighter requirements on the initial accuracy and stability of the reference source.

In general, the magnitude of the reference voltage will require an initial adjustment. Errors due to an improper value of reference voltage appear as full-scale errors in the $A / D$ transfer function. IC voltage regulators may be used for references if the ambient temperature changes are not excessive. The LM336B 2.5V IC reference diode (from National Semiconductor) is available which has a temperature stability of 1.8 mV typ ( 6 mV max)
over $0^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+70^{\circ} \mathrm{C}$. Other temperature range parts are also available.

### 2.5 Errors and Reference Voltage Adjustments

### 2.5.1 Zero Error

The zero of the A/D does not require adjustment. If the minimum analog input voltage value, $V_{I N}(M I N)$, is not ground, a zero offset can be done. The converter can be made to output 00000000 digital code for this minimum input voltage by biasing the $A / D V_{I N}(-)$ input at this $V_{I N}($ MIN ) value (see Applications section). This utilizes the differential mode operation of the $A / D$.

The zero error of the $A / D$ converter relates to the location of the first riser of the transfer function and can be measured by grounding the $\vee(-)$ input and applying a small magnitude positive voltage to the $\mathrm{V}(+)$ input. Zero error is the difference between the actual DC input voltage which is necessary to just cause an output digital code transition from 00000000 to 0000 0001 and the ideal $1 / 2 \mathrm{LSB}$ value $(1 / 2 \mathrm{LSB}=9.8 \mathrm{mV}$ for $\left.V_{R E F} / 2=2.500 V_{D C}\right)$.

### 2.5.2 Full-Scale

The full-scale adjustment can be made by applying a differential input voltage which is $1-1 / 2$ LSB down from the desired analog full-scale voltage range and then adjusting the magnitude of the $V_{\text {REF }} / 2$ input (pin 9 or the $V_{C C}$ supply if pin 9 is not used) for a digital output code which is just changing from 11111110 to 11111111.

### 2.5.3 Adjusting for an Arbitrary Analog Input Voltage Range

If the analog zero voltage of the $A / D$ is shifted away from ground (for example, to accommodate an analog input signal which does not go to ground) this new zero reference should be properly adjusted first. A $\mathrm{V}_{\text {IN }}(+)$ voltage which equals this desired zero reference plus $1 / 2$ LSB (where the LSB is calculated for the desired analog span, 1 LSB = analog span/256) is applied to pin 6 and the zero reference voltage at pin 7 should then be adjusted to just obtain the 00 HEX to 01 HEX code transition.

The full-scale adjustment should then be made (with the proper $\mathrm{V}_{\mathbf{I N}}(-)$ voltage applied) by forcing a voltage to the $\mathrm{V}_{\text {IN }}{ }^{(+)}$input which is given by:

$$
V_{\text {IN }}(+) \text { fs adj }=V_{M A X}-1.5\left[\frac{\left(V_{M A X}-V_{M I N}\right)}{256}\right]
$$

where:
$\mathrm{V}_{\mathrm{MAX}}=$ The high end of the analog input range
and
$\mathrm{V}_{\mathrm{MIN}}=$ the low end (the offset zero) of the analog range. (Both are ground referenced.)
The $V_{R E F} / 2$ (or $V_{C C}$ ) voltage is then adjusted to provide a code change from $\mathrm{FE}_{\text {HEX }}$ to FFHEX. This completes the adjustment procedure.

### 2.6 Clocking Option

The clock for the $A / D$ can be derived from the CPU clock or an external RC can be added to provide selfclocking. The .CLK IN (pin 4) makes use of a Schmitt trigger as shown in Figure 6.


FIGURE 6. Self-Clocking the A/D
Heavy capacitive or DC loading of the clock $R$ pin should be avoided as this will disturb normal converter operation. Loads less than 50 pF , such as driving up to 7 A/D converter clock inputs from a single clock $R$ pin of 1 converter, are allowed. For larger clock line loading, a CMOS or low power. T ${ }^{2}$ L buffer or PNP input logic should be used to minimize the loading on the clock $R$ pin (do not use a standard $T^{2} L$ buffer).

### 2.7 Restart During a Conversion

If the $A / D$ is restarted ( $\overline{\mathrm{CS}}$ and $\overline{\mathrm{WR}}$ go low and return high) during a conversion, the converter is reset and a new conversion is started. The output data latch is not updated if the conversion in process is not allowed to
be completed, therefore the data of the previous conversion remains in this latch. The TNTR output also simply remains at the " 1 " level.

### 2.8 Continuous Conversions

For operation in the free-running mode an initializing pulse should be used, following power-up, to insure circuit operation. In this application, the $\overline{\mathrm{CS}}$ input is grounded and the $\overline{W R}$ input is tied to the $\overline{\text { INTR }}$ output. This $\overline{W R}$ and $\overline{\text { INTR }}$ node should be momentarily forced to logic low following a power-up cycle to guarantee operation.

### 2.9 Driving the Data Bus

This MOS A/D, like MOS microprocessors and memories, will require a bus driver when the total capacitance of the data bus gets large. Other circuitry, which is tied to the data bus, will add to the total capacitive loading, even in TRI-STATE (high impedance mode). Backplane bussing also greatly adds to the stray capacitance of the data bus.

There are some alternatives available to the designer to handle this problem. Basically, the capacitive loading of the data bus slows down the response time, even though DC specifications are still met. For systems operating with a relatively slow CPU clock frequency, more time is available in which to establish proper logic levels on the bus and therefore higher capacitive loads can be driven (see typical characteristics curves).

At higher CPU clock frequencies time can be extended for $1 / O$ reads (and/or writes) by inserting wait states (8080) or using clock extending circuits (6800).

Finally, if time is short and capacitive loading is high, external bus drivers must be used. These can be TRISTATE buffers (low power 'Schottky is recommended such as the DM74LS240 series) or special higher drive current products which are designed as bus drivers. High current bipolar bus drivers with PNP inputs are recommended.

### 2.10 Power Supplies

Noise spikes on the $\mathrm{V}_{\mathrm{CC}}$ supply line can cause conversion errors as the comparator will respond to this noise. A low inductance tantalum filter capacitor should be used close to the converter $\mathrm{V}_{\mathrm{CC}}$ pin and values of $1 \mu \mathrm{~F}$ or greater are recommended. If an unregulated voltage is available in the system, a separate LM340LAZ-5.0, TO-92, 5 V voltage regulator for the converter (and other analog circuitry) will greatly reduce digital noise on the $\mathrm{V}_{\mathrm{CC}}$ supply.

### 2.11 Wiring and Hook-Up Precautions

Standard digital wire wrap sockets are not satisfactory for breadboarding this A/D converter. Sockets on PC boards can be used and all logic signal wires and leads should be grouped and kept as far away as possible from the analog signal leads. Exposed leads to the analog inputs can cause undesired digital noise and hum pickup, therefore shielded leads may be necessary in many applications.

A single point analog ground should be used which is separate from the logic ground points. The power supply bypass capacitor and the self-clocking capacitor (if used) should both be returned to digital ground. Any $V_{R E F} / 2$ bypass capacitors, analog input filter capacitors, or input signal shielding should be returned to the analog ground point. A test for proper grounding is to measure the zero error of the $A / D$ converter. Zero errors in excess of 1/4 LSB can usually be traced to improper board layout and wiring (see section 2.5.1 for measuring the zero error).

### 3.0 TESTING THE A/D CONVERTER

There are many degrees of complexity associated with testing an A/D converter. One of the simplest tests is to apply a known analog input voltage to the converter and use LEDs to display the resulting digital output code as shown in Figure 7.

For ease of testing, the $V_{R E F} / 2$ (pin 9) should be supplied with $2.560 V_{D C}$ and a VCC supply voltage of 5.12 VDC should be used. This provides an LSB value of 20 mV .

If a full-scale adjustment is to be made, an analog input voltage of $5.090 \operatorname{VDC}(5.120-11 / 2 \mathrm{LSB})$ should be applied to the $V_{I N}(+)$ pin with the $V_{I N}(-)$ pingrounded. The value of the $V_{\text {REF }} / 2$ input voltage should then be adjusted until the digital output code is just changing from 11111110 to 1111 1111. This value of VREF/2 should then be used for all the tests.
The digital output LED display can be decoded by dividing the 8 bits into 2 hex characters, the 4 most significant (MS) and the 4 least significant (LS). Table 1 shows the fractional binary equivalent of these two 4-bit groups. By adding the decoded voltages which are obtained from the column: Input voltage value for a 2.560 $V_{\text {REF }} / 2$ of both the MS and the LS groups, the value of
the digital display can be determined. For example, for an output LED display of 10110110 or B6 (in hex), the voltage values from the table are $3.520+0.120$ or 3.640 VDC. These voltage values represent the centervalues of a perfect $A / D$ converter. The effects of quantization error have to be accounted for in the interpretation of the test results.

For a higher speed test system, or to obtain plotted data, a digital-to-analog converter is needed for the test set-up. An accurate 10 -bit DAC can serve as the precision voltage source for the $A / D$. Errors of the $A / D$ under test can be provided as either analog voltages or differences in 2 digital words.

A basic A/D tester which uses a DAC and provides the error as an analog output voltage is shown in Figure 8. The 2 op amps can be eliminated if a lab DVM with a numerical subtraction feature is available to directly readout the difference voltage, "A-C". The analog input voltage can be supplied by a low frequency ramp generator and an $X-Y$ plotter can be used to provide analog error ( $Y$ axis) versus analog input ( $X$ axis). The construction details of a tester of this type are provided in the NSC application note AN-179, "Analog-to-Digital Converter Testing".

For operation with a microprocessor or a computerbased test system, it is more convenient to present the errors digitally. This can be done with the circuit of Figure 9, where the output code transitions can be detected as the 10 -bit DAC is incremented. This provides $1 / 4$ LSB steps for the 8 -bit $A / D$ under test. If the results of this test are automatically plotted with the analog input on the $X$ axis and the error (in LSB's) as the $Y$ axis, a useful transfer function of the $A / D$ under test results. For acceptance testing, the plot is not necessary and the testing speed can be increased by establishing internal limits on the allowed error for each code.


FIGURE 7. Basic A/D Tester


* V Display Output $=$ VMS Group + VLS Group


### 4.0 MICROPROCESSOR INTERFACING

To discuss the interface with 8080A, 6800 and SC/MP-II microprocessors, a common sample subroutine structure is used. The microprocessor starts the $A / D$, reads and stores the results of 16 successive conversions, then returns to the user's program. The 16 data bytes are stored at location 0200 to 020F. All Data and Addresses will be given in hexadecimal form. Software and hardware details are provided separately for each type of microprocessor.

### 4.1 Interfacing 8080 Microprocessor Derivatives (8048, 8085)

This converter has been designed to directly interface with derivatives of the 8080 microprocessor. The A/D can be mapped into memory space (using standard memory address decoding for CS and the MEMR and MEMW strobes) or it can be controlled as an I/O device by using the $\overline{1 / O R}$ and $\overline{1 / O W}$ strobes and decoding the address bits A0 $\rightarrow$ A7 (or address bits A8 $\rightarrow$ A15 as they will contain the same 8 -bit address information) to obtain the $\overline{\mathrm{CS}}$ input. Using the I/O space provides 256 additional addresses and may allow a simpler 8 -bit address decoder but the data can only be input to the accumulator. To make use of the additional memory reference instructions, the $A / D$ should be mapped into memory space. An example of an A/D in I/O space is shown in Figure 10.

The standard control bus signals of the $8080(\overline{\mathrm{CS}}, \overline{\mathrm{RD}}$ and $\overline{W R}$ ) can be directly wired to the digital control inputs of the $A / D$ and the bus timing requirements are met to allow both starting the converter and outputting the data onto the data bus. A bus driver should be used for larger microprocessor systems where the data bus leaves the PC board and/or must drive capacitive loads larger than 100 pF .

### 4.1.1 Sample 8080A CPU Interfacing Circuitry and Program

The following sample program and associated hardware may be used to input data from the converter to the INS8080A CPU chip set (comprised of the INS8080A microprocessor, the INS8228 system controller and the INS8224 clock generator). For simplicity, the A/D is controlled as an I/O device, specifically an 8 -bit bidirectional port located at an arbitrarily chosen port address, EO. The TRI-STATE output capability of the A/D eliminates the need for a peripheral interface device, however address decoding is still required to generate the appropriate $\overline{\mathrm{CS}}$ for the converter.

It is important to note that in systems where the $A / D$ converter is 1 -of-8 or less I/O mapped devices, no address decoding circuitry is necessary. Each of the 8 address bits ( $A 0$ to $A 7$ ) can be directly used as $\overline{C S}$ inputs-one for each I/O device.


Note 1: *Pin numbers for the INS8228 system controller, others are INS8080A.
Note 2: Pin 23 of the INS8228 must be tied to +12 V through a $1 \mathrm{k} \Omega$ resistor to generate the RST 7 instruction when an interrupt is acknowledged as required by the accompanying sample program.

FIGURE 10. ADC0801-INS8080A CPU Interface

## SAMPLE PROGRAM FOR FIGURE 10 ADC0801-INS8080A CPU INTERFACE

| 0038 | C3 0003 | RST 7: | JMP LD DATA |  |
| :---: | :---: | :---: | :---: | :---: |
| - | . | - |  |  |
|  |  |  |  |  |
| 0100 | 210002 | START: | LXI H 0200H | ; HL pair will point to <br> ; data storage locations |
| 0103 | 310004 | RETURN: | LXI SP 0400H | Initialize stack pointer (Note 1) |
| 0106 | 7D |  | MOV A, L | ; Test \# of bytes entered |
| 0107 | FE OF |  | CPI OF H | If \# = 16. JMP to |
| 0109 | CA 1301 |  | JZ CONT | user program |
| 010C | D3 E0 |  | OUT EOH | ; Start A/D |
| 010E | FB |  | El | Enable interrupt |
| 010F | 00 | LOOP: | NOP | Loop until end of |
| 0110 | C3 OF 01 |  | JMP LOOP | ; conversion |
| 0113 | . | CONT: | . |  |
| - | - | - | - |  |
| . | . | (User program to | . |  |
| . | - | process data) | . । |  |
| - | - | . | . |  |
|  |  |  | - |  |
| 0300 | DB EO | LD DATA: | IN EOH | Load data into accumulator |
| 0302 | 77 |  | MOV M, A | ; Store data |
| 0303 | 23 |  | INX H | Increment storage pointer |
| 0304 | C3 0301 |  | JMP RETURN |  |

Note 1: The stack pointer must be dimensioned because a RST 7 instruction pushes the PC onto the stack.
Note 2: All addresses used were arbitrarily chosen.

### 4.2 Interfacing the Z-80

The Z-80 control bus is slightly different from that of the 8080. General $\overline{R D}$ and $\overline{W R}$ strobes are provided and separate memory request, $\overline{\mathrm{MREQ}}$, and I/O request, $\overline{\text { IORQ, signals are used which have to be combined with }}$ the generalized strobes to provide the equivalent 8080 signals. An advantage of operating the A/D in I/O space with the $\mathrm{Z}-80$ is that the CPU will automatically insert one wait state (the $\overline{R D}$ and $\overline{W R}$ strobes are extended one clock period) to allow more time for the I/O devices to respond. Logic to map the A/D in I/O space is shown in Figure 11.


FIGURE 11. Mapping the $A / D$ as an I/O Device for Use with the Z-80 CPU

Additional I/O advantages exist as software DMA routines are available and use can be made of the output data transfer which exists on the upper 8 address lines (A8 to A15) during I/O input instructions. For example, MUX channel selection for the A/D can be accomplished with this operating mode.

### 4.3 Interfacing 6800 Microprocessor Derivatives (6502, etc.)

The control bus for the 6800 microprocessor derivatives does not use the $\overline{\mathrm{RD}}$ and $\overline{W R}$ strobe signals. Instead it employs a single $R / \bar{W}$ line and additional timing, if needed, can be derived from the $\phi 2$ clock. All I/O devices are memory mapped in the 6800 system, and a special signal, VMA, indicates that the current address is valid. Figure 12 shows an interface schematic where the A/D is memory mapped in the 6800 system. For simplicity, the $\overline{C S}$ decoding is shown using 1/2 DM8092. Note that in many 6800 systems, an already decoded $\overline{4 / 5}$ line is brought out to the common bus at pin 21 . This can be tied directly to the $\overline{C S}$ pin of the $A / D$, provided that no other devices are addressed at HEX ADDR: $4 X X X$ or $5 X X X$.

The following subroutine essentially performs the same function as in the case of the 8080A interface and it can be called from anywhere in the user's program.

In Figure 13 the ADC0801 series is interfaced to the M6800 microprocessor through (the arbitrarily chosen) Port B of the MC6820 or MC6821 Peripheral Interface Adapter, (PIA). Here the $\overline{C S}$ pin of the A/D is grounded since the PIA is already memory mapped in the M6800 system and no $\overline{\mathrm{CS}}$ decoding is necessary. Also notice that the A/D output data lines are connected to the microprocessor bus under program control through the PIA and therefore the $\mathrm{A} / \mathrm{D} \overline{\mathrm{RD}}$ pin can be grounded.

## SAMPLE PROGRAM FOR FIGURE 12 ADC0801-MC6800 CPU INTERFACE

| 0010 | DF 36 | DATAIN | STX | TEMP2 | ; Save contents of $X$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0012 | CE 00 2C |  | LDX | \#\$002C | ; Upon $\overline{\mathrm{RQ}}$ low CPU |
| 0015 | FF FF F8 |  | STX | \$FFF8 | ; jumps to 002C |
| 0018 | B7 5000 |  | STAA | \$5000 | ; Starts ADC0801 |
| 001B | OE |  | CLI |  |  |
| 001C | 3E | CONVRT | WAI |  | ; Wait for interrupt |
| 001D | DE 34 |  | LDX | TEMP1 |  |
| 001F | 8C 02 OF |  | CPX | \#\$020F | ; Is final data stored? |
| 0022 | 2714 |  | BEO | ENDP |  |
| 0024 | B7 5000 |  | STAA | \$5000 | ; Restarts ADC0801 |
| 0027 | 08 |  | INX |  |  |
| 0028 | DF 34 |  | STX | TEMP1 |  |
| 002A | 20 FO |  | BRA | CONVRT |  |
| 002C | DE 34 | INTRPT | LDX | TEMP1 |  |
| 002E | B6 5000 |  | LDAA | \$5000 | ; Read data |
| 0031 | A7 00 |  | STAA | X | ; Store it at X |
| 0033 | 3B |  | RTI |  |  |
| 0034 | 0200 | TEMP1 | FDB | \$0200 | ; Starting address for <br> ; data storage |
| 0036 | 0000 | TEMP2 | FDB | \$0000 |  |
| 0038 | CE 0200 | ENDP | LDX | \#\$0200 | ; Reinitialize TEMP1 |
| 003B | DF 34 |  | STX | TEMP1 |  |
| 003D | DE 36 |  | LDX | TEMP2 |  |
| 003F | 39 |  | RTS |  | ; Return from subroutine <br> - To user's program |

Note 1: In order for the microprocessor to service subroutines and interrupts, the stack pointer must be dimensioned in the user's program.


Note 1: Numbers in parentheses refer to MC6800 CPU pin out.
Note 2: Numbers or letters in, brackets refer to standard M6800 system common bus code.
FIGURE 12. ADC0801-MC6800 CPU Interface


FIGURE 13. ADC0801-MC6820 PIA Interface

A sample interface program equivalent to the previous one, is shown below. The PIA Data and Control Registers of Port B are located at HEX addresses 8006 and 8007, respectively.

### 4.4 Interfacing the INS8060-SC/MP-II

The SC/MP-II interface technique with the ADC0801 series Figure 14, is similar to the 8080A CPU interface.

SAMPLE PROGRAM FOR FIGURE 13 ADC0801-MC6820 PIA INTERFACE

| 0010 | CE 0038 | DATAIN | LDX | \#\$0038 | ; Upon $\overline{\text { RQ }}$ low CPU |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0013 | FF FF F8 |  | STX | \$FFF8 | ; jumps to 0038 |
| 0016 | B6 8006 |  | LDAA | PIAORB | ; Clear possible $\overline{\mathrm{IRO}}$ flags |
| 0019 | 4 F |  | CLRA |  |  |
| 001A | B7 8007 |  | STAA | PIACRB |  |
| 001D | B7 8006 |  | STAA | PIAORB | ; Set Port B as input |
| 0020 | OE |  | CLI |  |  |
| 0021 | C6 34 |  | LDAB | \#\$34 |  |
| 0023 | 863 D |  | LDAA | \#\$3D |  |
| 0025 | F7 8007 | CONVRT | STAB | PIACRB | ; Starts ADC0801 |
| 0028 | B7 8007 |  | STAA | PIACRB |  |
| 002B | 3 E |  | WAI |  | ; Wait for interrupt |
| 002C | DE 40 |  | LDX | TEMP1. |  |
| 002E | 8 C 02 OF |  | CPX | \#S020F | ; Is final data stored? |
| 0031 | 27 0F |  | BEQ | ENDP |  |
| 0033 | 08 |  | INX |  |  |
| 0034 | DF 40 |  | STX | TEMP1 |  |
| 0036 | 20 ED |  | BRA | CONVRT |  |
| 0038 | DE 40 | INTRPT | LDX | TEMP1 |  |
| 003A | B6 8006 |  | LDAA | PIAORB | ; Read data in |
| 003D | A7 00 |  | STAA | X | ; Store it at X |
| 003F | 3B |  | RTI |  |  |
| 0040 | 0200 | TEMP1 | FDB | \$0200 | ; Starting address for ; data storage |
| 0042 | CE 0200. | ENDP | LDX | \#\$0200 | ; Reinitialize TEMP1 |
| 0045 | DF 40 |  | STX | TEMP1 |  |
| 0047 | 39 |  | RTS |  | ; Return from subroutine |
|  |  | PIAORB | EQU | \$8006 | ; To user's program |
|  |  | PIACRB | EQU | \$8007 |  |


*Pin numbers in parentheses are for the SC/MP CPU.
FIGURE 14. ADC0801-SC/MP-II Microprocessor Interface

The $A / D$ is treated as a peripheral and it is mapped into the memory space of the SC/MP-11 system. An address, ODOO, is assigned to the A/D and the $\overline{C S}$ signal is shown to be decoded by a bus comparator, DM8131. The $\overline{\mathrm{RD}}$ and $\overline{W R}$ pins of the $A / D$ are tied directly to the Write Data Strobe, NWRS, and Read Data Strobe, NRDS, pins of the SC/MP-II CPU. Notice that the INTR signal should be inverted before being tied to the SENSE A pin of the SC/MP-II. A sample interface program is shown below.

### 5.0 GENERAL APPLICATIONS

The following applications show some interesting uses for the A/D. The fact that one particular microprocessor is used is not meant to be restrictive. Each of these appli-
cation circuits would have its counterpart using any microprocessor which is desired.

### 5.1 Multiple ADC0801 Series to MC6800 CPU Interface

To transfer analog data from several channels to a single microprocessor system, a multiple converter scheme presents several advantages over the conventional multiplexer single-converter approach. With the ADC0801 series, the differential inputs allow individual span adjustment for each channel. Furthermore, all analog input channels are sensed simultaneously, which essentially divides the microprocessor's total system servicing time by the number of channels, since all conversions occur simultaneously. This scheme is shown in Figure 15.

SAMPLE PROGRAM FOR FIGURE 14 ADC0801-SC/MP-II MICROPROCESSOR INTERFACE

| 0100 | 08 |  |  | NOP |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0101 | C4 | 02 |  | LDIO2 |  |
| 0103 |  | 35 |  | XPAH(P1) |  |
| 0104 | C4 | OD |  | LDIOD |  |
| 0106 |  | 36 |  | XPAH(P2) |  |
| 0107 | C4 | 03 |  | LDI03 |  |
| 0109 |  | 37 |  | XPAH(P3) |  |
| 010A | C4 | 00 | . | LDIOO |  |
| 010C |  | 31 |  | XPAL(P1) | ; $\mathrm{P} 1=0200, \mathrm{P} 1$ points to 1st byte address |
| 010D | C4 | 00 |  | LDIOO |  |
| 010F | C9 | $11$ |  | ST(P1+11)XPAL(P2) | ; Zero the byte count in address 0211 <br> ; P2=0D00, P2 points to A/D |
| 0112 |  | 32 |  |  |  |
| 0113 | CA | 00 | START: |  | ; START the A/D |
| 0115 | C4 | 00 |  | LDIOO |  |
| 0117 |  | 33 |  | XPAL(P3) | ; $\mathrm{P} 3=0300, \mathrm{P} 3$ points to DATA in sub. ; starting address |
| 0118 |  | 05 |  | IEN |  |
| 0119 |  | 08 | LOOP: | NOP |  |
| 011A | 90 | FE |  | JMP(LOOP) |  |
|  |  |  | User's Progr |  |  |
| 011C |  |  | USER | NOP |  |
| 011D |  |  |  | NOP |  |
|  |  |  |  | . |  |
|  |  |  |  | - . |  |
| 0300 | C2 | 00 | DATA IN: | LD(P2) | ; Load A/D data into accumulator |
| 0302 | CD | 01 |  | ST@1(P1) | ; Store A/D data and increment byte ; address |
| 0304 | A9 | 11 |  | 1LD(P1+11) | ; Increment byte count |
| 0306 | C4 | OF |  | LDIOF |  |
| 0308 |  | 03 |  | SCL |  |
| 0309 | F9 | 11 |  | CAD (P1+11) | ; $0 F-\langle P 1+11\rangle$ : Is byte count $=16$ ? |
| 030B | 9 B | 03 |  | JZ(USER) | ; If byte count $=16$ jump to user's ; program |
| 030D | C4 | 13 |  | LDI13 |  |
| 030F |  | 33 |  | XPAL(P3) | ; P3=0113 |
| 0310 |  | 3 F |  | XPPC(P3) | ; Go to START and do another conversion |

The following schematic and sample subroutine (DATA IN) may be used to interface (up to) 8 ADC0801's directly to the MC6800 CPU. This scheme can easily be extended to allow the interface of more converters. In this configuration the converters are (arbitrarily) located at HEX address 5000 in the MC6800 memory space. To save components, the clock signal is derived from just one RC pair on the first converter. This output drives the other A/Ds.

All the converters are started simultaneously with a STORE instruction at HEX address 5000. Note that any other HEX address of the form $5 \times X X$ will be decoded by the circuit, pulling all the $\overline{\mathrm{CS}}$ inputs low. This can easily be avoided by using a more definitive address decoding scheme. All the interrupts are ORed together to insure that all $A / D s$ have completed their conversion before the microprocessor is interrupted.

The subroutine, DATA IN, may be called from anywhere in the user's program. Once called, this routine initializes
the CPU, starts all the converters simultaneously and waits for the interrupt signal. Upon receiving the interrupt, it reads the converters (from HEX addresses 5000 through 5007) and stores the data successively at (arbitrarily chosen) HEX addresses 0200 to 0207 , before returning to the user's program. All CPU registers then recover the original data they had before servicing DATA IN .

### 5.2 Auto-Zeroed Differential Transducer Amplifier and A/D Converter

The differential inputs of the ADC0801 series eliminate the need to perform a differential to single ended conversion for a differential transducer. Thus, one op amp can be eliminated since the differential to single ended conversion is provided by the differential input of the ADC0801 series. In general, a transducer preamp is required to take advantage of the full A/D converter input dynamic range.


Note 1: Numbers in parentheses refer to MC6800 CPU pin out.
Note 2: Numbers or letters in brackets refer to standard M6800 system common bus code.
FIGURE 15. Interfacing Multiple A/Ds in an MC6800 System

| ADDRESS | HEX CODE | MNEMONICS |  |  | COMMENTS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0010 | DF 44 | DATAIN | STX | TEMP | ; Save Contents of X |
| 0012 | CE 00 2A |  | LDX | \#\$002A | ; Upon $\overline{\mathrm{RO}}$ LOW CPU |
| 0015 | FF FF F8 |  | STX | \$FFF8 | ; Jumps to 002A |
| 0018 | B7 5000 |  | STAA | \$5000 | ; Starts all A/D's |
| 001B | OE |  | CLI |  |  |
| 001C | 3E |  | WAI |  | ; Wait for interrupt |
| 001D | CE 5000 |  | LDX | \#\$5000 |  |
| 0020 | DF 40 |  | STX | INDEX1 | ; Reset both INDEX |
| 0022 | CE 0200 |  | LDX | \#\$0200 | ; 1 and 2 to starting |
| 0025 | DF 42 |  | STX | INDEX2 | ;addresses |
| 0027 | DE 44 |  | LDX | TEMP |  |
| 0029 | 39 |  | RTS |  | ; Return from subroutine |
| 002A | DE 40 | INTRPT | LDX | INDEX1 | ; INDEX1 $\rightarrow$ X |
| 002C | A6 00 |  | LDAA | X | ; Read data in from A/D at $X$ |
| 002E | 08 |  | INX |  | ; Increment X by one |
| 002F | DF 40 |  | STX | INDEX1 | ; $\mathrm{X} \rightarrow$ INDEX 1 |
| 0031 | DE 42 |  | LDX | INDEX2 | ; INDEX2 $\rightarrow$ X |
| 0033 | A7 00 |  | STAA | X | ;Store data at X |
| 0035 | 8С 0207 |  | CPX | \#\$0207 | ;Have all A/D's been read? |
| 0038 | 2705 |  | BEO | RETURN | ;Yes: branch to RETURN |
| 003A | 08 |  | INX |  | ;No: increment X by one |
| 003B | DF 42 |  | STX | INDEX2 | ; $\mathrm{X} \rightarrow$ INDEX2 |
| 003D | 20 EB |  | BRA | INTRPT | ;Branch to 002A |
| 003F | 3B | RETURN | RTI |  |  |
| 0040 | 5000 | INDEX1 | FDB | \$5000 | ;Starting address for A/D |
| 0042 | 0200 | INDEX2 | FDB | \$0200 | ;Starting address for data storage |
| 0044 | 0000 | TEMP | FDB | \$0000 |  |

Note 1: In order for the microprocessor to service subroutines and interrupts, the stack pointer must be dimensioned in the user's program.

For amplification of DC input signals, a major system error is the input offset voltage of the amplifiers used for the preamp. Figure 16 is a gain of 100 differential preamp whose offset voltage errors will be cancelled by a zeroing subroutine which is performed by the INS8080A microprocessor system. The total allowable input offset voltage error for this preamp is only $50 \mu \mathrm{~V}$ for $1 / 4$ LSB error. This would obviously require very precise amplifiers. The expression for the differential output voltage of the preamp is:

$$
\begin{aligned}
& V_{\text {OIGNAL }}^{\left[V_{I N}(+)-V_{I N}(-)\right]} \underbrace{\left[1+\frac{2 R 2}{R 1}\right]}_{\text {GAIN }}+ \\
& \underbrace{\left(V_{O S 2}-V_{O S 1}-V_{O S 3} \pm I_{x} R_{x}\right)}_{\text {DC ERROR TERM }} \underbrace{\left(1+\frac{2 R 2}{R 1}\right)}_{\text {GAIN }}
\end{aligned}
$$

where $I_{X}$ is the current through resistor $R_{X}$. All of the offset error terms can be cancelled by making $\pm I_{x} R_{X}=$ $V_{o s 1}+V_{o s 3}-V_{o s 2}$. This is the principle of this auto-zeroing scheme.

The INS8080A uses the 3 I/O ports of an INS8255 Programmable Peripheral Interface (PPI) to control the auto zeroing and input data from the ADC0801 as shown in rigure 17. The PPI is programmed for basic I/O operation (mode 0 ) with Port A being an input port and Ports $B$ and $C$ being output ports. Two bits of Port $C$ are used to alternately open or close the 2 switches at the input
of the preamp. Switch SW1 is closed to force the preamp's differential input to be zero during the zeroing subroutine and then opened and SW2 is then closed for conversion of the actual differential input signal. Using 2 switches in this manner eliminates concern for the ON resistance of the switches as they must conduct only the input bias current of the input amplifiers.

Output Port B is used as a successive approximation register by the 8080 and the binary scaled resistors in series with each output bit create a D/A converter. During the zeroing subroutine, the voltage at $V_{x}$ increases or decreases as required to make the differential output voltage equal to zero. This is accomplished by insuring that the voltage at the output of A1 is approximately 2.5 V so that a logic " 1 " $(5 \mathrm{~V})$ on any output of Port $B$ will source current into node $V_{X}$ thus raising the voltage at $\mathrm{V}_{\mathrm{X}}$ and making the output differential more negative. Conversely, a logic " 0 " ( 0 V ) will pull current out of node $V_{X}$ and decrease the voltage, causing the differential output to become more positive. For the resistor values shown, $V_{x}$ can move $\pm 12 \mathrm{mV}$ with a resolution of $50 \mu \mathrm{~V}$ which will null the offset error term to $1 / 4$ LSB of full-scale for the ADC0801. It is important that the voltage levels which drive the autozero resistors be constant. Also, for symmetry, a logic swing of 0 V to 5 V is convenient. To achieve this, a CMOS buffer is used for the logic output signals of Port $B$ and this CMOS package is powered with a stable 5 V source. Buffer amplifier A1 is necessary so that it can source or sink the D/A output current.


Note 1: R2 = 49.5 R1
Note 2: Switches are CD4066BC CMOS analog switches.
Note 3: The 9 resistors used in the auto-zero section can be $\pm 5 \%$ tolerance.
FIGURE 16. Gain of 100 Differential Transducer Preamp


FIGURE 17. Microprocessor Interface Circuitry for Differential Preamp

A flow chart for the zeroing subroutine is shown in Figure 18. It must be noted that the ADC0801 series will output an all zero code when it converts a negative input $\left[V_{I N}(-) \geq V_{I N}(+)\right]$. Also, a logic inversion exists as all of the I/O ports are buffered with inverting gates.

Basically, if the data read is zero, the differential output voltage is negative, so a bit in Port $B$ is cleared to pull $\mathrm{V}_{\mathrm{X}}$ more negative which will make the output more positive for the next conversion. If the data read is not zero, the output voltage is positive so a bit in Port B is set to make $V_{X}$ more positive and the output more negative. This continues for 8 approximations and the differential output eventually converges to within 5 mV of zero.

The actual program is given in Figure 19. All addresses used are compatible with the BLC 80/10 microcomputer system. In particular:

Port A and the ADC0801 are at port address E4
Port $B$ is at port address E5
Port C is at port address E6
PPI control word port is at port address E7
Program Counter automatically goes to ADDR:3C3D upon acknowledgement of an interrupt from the ADC0801

### 5.3 Multiple A/D Converters in a Z-80 Interrupt Driven Mode

In data acquisition systems where more than one $A / D$ converter (or other peripheral device) will be interrupting program execution of a microprocessor, there is obviously a need for the CPU to determine which device requires servicing. Figure 20 and the accompanying software is a method of determining which of 7 ADC0801 converters has completed a conversion (INTR asserted) and is requesting an interrupt. This circuit allows starting the $A / D$ converters in any sequence, but will input and store valid data from the converters with a priority sequence of $A / D 1$ being read first, A/D 2 second, etc., through A/D 7 which would have the lowest priority for data being read. Only the converters whose INT is asserted will be read.

The key to decoding circuitry is the DM74LS373, 8 -bit $D$ type flip-flop. When the Z-80 acknowledges the interrupt, the program is vectored to a data input Z-80 subroutine. This subroutine will read a peripheral status word from the DM74LS373 which contains the logic state of the INTR outputs of all the converters. Each converter which initiates an interrupt will place a logic " 0 " in a unique bit position in the status word and the subroutine will determine the identity of the converter and execute a data read. An identifier word (which indicates which A/D the data came from) is stored in the next sequential memory location above the location of the data so the program can keep track of the identity of the data entered.


| 3D00 | 3 E90 | MVI 90 |  |  |
| :---: | :---: | :---: | :---: | :---: |
| 3D02 | D3E7 | Out Control Port |  | ; Program PPI |
| 3D04 | 2601 | MVI H 01 | Auto-Zero Subroutine |  |
| 3D06 | 7 C | MOV A,H |  |  |
| 3 D 07 | D3E6 | OUT C |  | ; Close SW1, open SW2 |
| 3D09 | 0680 | MVI B 80 |  | ; Initialize SAR bit pointer |
| 3D0B | 3E7F | MVI A 7F |  | ; Initialize SAR code |
| 3DOD | 4F | MOV C,A | Return |  |
| 3D0E | D3E5 | OUT B |  | ; Port B = SAR code |
| 3D10 | 31AA3D | LXI SP 3DAA | Start | ; Dimension stack pointer |
| 3D13 | D3E4 | OUT A |  | ; Start A/D |
| 3D15 | FB | IE |  |  |
| 3D16 | 00 | NOP | Loop | ; Loop until $\overline{\mathrm{NT}}$ asserted |
| 3D17 | C3163D | JMP Loop |  |  |
| 3D1A | 7A | MOV A, D | Auto-Zero |  |
| 3D1B | C600 | ADI 00 |  |  |
| 3D1D | CA2D3D | JZ Set C |  | ; Test A/D output data for zero |
| 3D20 | 78 | MOV A,B | Shift B |  |
| 3D21 | F600 | ORI 00 |  | ; Clear carry |
| 3D23 | 1F | RAR |  | ; Shift "1" in B right one place |
| 3D24 | FE00 | CPI 00 |  | ; Is B zero? If yes last |
| 3D26 | CA373D | JZ Done |  | ; approximation has been made |
| 3D29 | 47 | MOV B,A |  |  |
| 3D2A | C3333D | JMP New C |  |  |
| 3D2D | 79 | MOV A,C | Set C |  |
| 3D2E | B0 | ORA B |  | ; Set bit in C that is in same |
| 3D2F | 4F | MOV C,A |  | ; position as " 1 " in B |
| 3D30 | C3203D | JMP Shift B |  |  |
| 3D33 | A9 | XRA C | New C | ; Clear bit in C that is in |
| 3D34 | C3003D | JMP Return |  | ; same position as " 1 " in B |
| 3 D 37 | 47 | MOV B,A | Done | ; then output new SAR code. |
| 3D38 | 7 C | MOV A, H |  | ; Open SW1, close SW2 then |
| 3D39 | EE03 | XRI 03 |  | ; proceed with program. Preamp |
| 3D3B | D3E6 | OUT C |  | ; is now zeroed. |
| 3D3D |  | . | Normal |  |
|  |  |  |  |  |
|  |  | Program for processing proper data values |  |  |
| 3C3D | DBE4 | IN A | Read A/D Subroutine | ; Read A/D data |
| 3C3F | EEFF | XRI FF |  | ; Invert data |
| 3 C 41 | 57 | MOV D,A |  |  |
| 3 C 42 | 78 | MOV A,B |  | ; Is B Reg $=0$ ? If not stay |
| 3 C 43 | E6FF | ANI FF | - | ; in auto zero subroutine |
| 3 C 45 | C21A3D | JNZ Auto-Zero |  |  |
| 3 C 48 | C33D3D | JMP Normal |  |  |

Note: All numerical values are hexadecimal representations.
FIGURE 19. Software for Auto-Zeroed Differential A/D

### 5.3 Multiple A/D Converters in a Z-80 Interrupt Driven Mode (Continued)

The following notes apply:

1) It is assumed that the CPU automatically performs a RST 7 instruction when a valid interrupt is acknowledged (CPU is in interrupt mode 1). Hence, the subroutine starting address of X0038.
2) The address bus from the $Z-80$ and the data bus to the $\mathrm{Z}-80$ are assumed to be inverted by bus drivers.
3) $A / D$ data and identifying words will be stored in sequential memory locations starting at the arbitrarily chosen address $X 3$ E00.
4) The stack pointer must be dimensioned in the main program as the RST 7 instruction automatically pushes the PC onto the stack and the subroutine uses an additional 6 stack addresses.
5) The peripherals of concern are mapped into $1 / O$ space with the following port assignments:

| HEX PORT ADDRESS | PERIPHERAL |
| :---: | :--- |
| 00 | MM74C374 8-bit flip-flop |
| 01 | A/D 1 |
| 02 | A/D 2 |
| 03 | A/D 3 |
| 04 | A/D 4 |
| 05 | A/D 5 |
| 06 | A/D 6 |
| 07 | A/D 7 |

This port address also serves as the A/D identifying word in the program.


FIGURE 20. Multiple A/Ds with Z-80 Type Microprocessor

| INTERRUPT SERVICING SUBROUTINE |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  |  | SOURCE |  |
| LOC | OBJ CODE |  | STATEMENT | COMMENT |
| 0038 | E5 |  | PUSH HL | Save contents of all registers affected by |
| 0039 | C5 |  | PUSH BC | , this subroutine. |
| 003A | F5 |  | PUSH AF | , Assumed INT mode 1 earlier set. |
| 003B | 21003 E |  | LD (HL), X3E00 | - Initialize memory pointer where data will be stored. |
| 003E | 0E 01 |  | LD C, X01 | : C register will be port ADDR of A/D converters. |
| 0040 | D300 |  | OUT X00,A | ; Load perıpheral status word into 8-bit latch. |
| 0042 | DB00 |  | IN A, X00 | ; Load status word into accumulator. |
| 0044 | 47 |  | LD B,A | ; Save the status word. |
| 0045 | 79 | TEST | LD A,C | ; Test to see if the status of all A/D's have |
| 0046 | FE 08 |  | CP, X08 | ; been checked. If so, exit subroutine. |
| 0048 | CA 6000 |  | JPZ, DONE |  |
| 004B | 78 |  | LD A,B | ; Test a single bit in status word by looking for |
| 004C | 1F |  | RRA | ; a "1" to be rotated into the CARRY (an INT |
| 004D | 47 |  | LD B,A | ; is loaded as a "1") If CARRY is set then load |
| 004E | DA 5500 |  | JPC, LOAD | ; contents of $A / D$ at port $A D D R$ in $C$ register. |
| 0051 | OC | NEXT | INC C | , If CARRY is not set, increment $C$ register to point |
| 0052 | C3 4500 |  | JP,TEST | ; to next A/D, then test next bit in status word. |
| 0055 | ED 78 | LOAD | IN A, (C) | , Read data from interrupting $A / D$ and invert |
| 0057 | EE FF |  | XOR FF | , the data. |
| 0059 | 77 |  | LD (HL), A | , Store the data. |
| 005A | 2C |  | INC L |  |
| 005B | 71 |  | LD (HL), C | , Store A/D ıdentifier (A/D port ADDR) |
| 005C | 2 C |  | INC L |  |
| 005D | C3 5100 |  | JP,NEXT | ; Test next bit in status word. |
| 0060 | F1 | DONE | POP AF | ; Re-establish all registers as they were |
| 0061 | C1 |  | POP BC | , before the interrupt |
| 0062 | E1 |  | POP HL |  |
| 0063 | C9 |  | RET | ; Return to original program. |

Section 4
CMOS Memory

## MM54C89/MM74C89 64-Bit TRI-STATE ${ }^{\text {® }}$ Random Access Read/Write Memory

## General Description

The MM54C89/MM74C89 is a 16-word by 4-bit random access read/write memory. Inputs to the memory consist of four address lines, four data input lines, a write enable line and a memory enable line. The four binary address inputs are decoded internally to select each of the 16 possible word locations. An internal address register, latches the address information on the positive to negative transition of the memory enable input. The four TRI-STATE ${ }^{\circledR}$ data output lines working in conjunction with the memory enable input provides for easy memory expansion.

Address Operation: Address inputs must be stable $\mathrm{t}_{\mathrm{SA}}$ prior to the positive to negative transition of memory enable. It is thus not necessary to hold address information stable for more than $t_{H A}$ after the memory is enabled (positive to negative transition of memory enable).

Note: The timing is different that the DM7489 in that a positive to negative transition of the memory enable must occur for the memory to be selected.

Write Operation: Information present at the data inputs is written into the memory at the selected address by bringing write enable and memory enable low.

TRI-STATE is a registered trademark of National Semiconductor Corp.

Read Operation: The complement of the information which was written into the memory is non-destructively read out at the four outputs. This is accomplished by selecting the desired address and bringing memory enable low and write enable high.

When the device is writing or disabled the output assumes a TRI-STATE (Hi-z) condition.

## Features

- Wide supply voltage range
3.0 V to 15 V
- Guaranteed noise margin
- High noise immunity
- Low power

TTL compatibility

- Low power consumption
$100 \mathrm{nW} /$ package (typ.)
Fast access time
130 ns (typ.) at $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$
- TRI-STATE output

Logic and Connection Diagrams



Order Number MM54C89D or MM74C89D See Package 3 Order Number MM74C89N See Package 15

Absolute Maximum Ratings (Note 1)

| Voltage at Any Pin | -0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$ |
| :--- | ---: |
| Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM54C89 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| MM74C89 | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |

Package Dissipation 500 mW
Operating $\mathrm{V}_{\mathrm{cc}}$ Range
3.0 V to 15 V

Absolute Maximum $\mathrm{V}_{\mathrm{Cc}} \quad 18 \mathrm{~V}$
Lead Temperature (Soldering, 10 seconds) $300^{\circ} \mathrm{C}$

DC Electrical Characteristics Min/max limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | CMOS to CMOS |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | V |
| $\mathrm{V}_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | 0.5 1.0 | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{I}_{\mathrm{IN}(1)}$ | Logical "1" Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | -0.005 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {IN(0) }}$ | Logical "0" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
|  | Output Current in High Impedance State | $\begin{aligned} & V_{C C}=15 \mathrm{~V}, \mathrm{~V}=15 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0 \mathrm{~V} \end{aligned}$ | -1.0 | $\begin{array}{r} 0.005 \\ -0.005 \end{array}$ | 1.0 | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |
| $\mathrm{I}_{\mathrm{CC}}$ | Supply Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 0.05 | 300 | $\mu \mathrm{A}$ |
|  | CMOS/LPTTL Interface |  |  |  |  |  |
| $\mathrm{V}_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}-1.5 \\ & \mathrm{~V}_{\mathrm{CC}}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical "0" Input Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $V_{\text {OUT(0) }}$ | Logical " 0 " Output Voltage | $\begin{aligned} & 54 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+360 \mu \mathrm{~A} \\ & 74 \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+360 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 0.4 \\ & \hline \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
|  | Output Drive (See 54C/74C Family Characteristics Data Sheet) (short circuit current) |  |  |  |  |  |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | -1.75 | $-3.3$ |  | mA |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | -8.0 | -15 |  | mA |
| ISINK | Output Sink Current ( N -Channel) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 1.75 | 3.6 |  | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current ( N -Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 8.0 | 16 |  | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Delay from Memory Enable | $\begin{aligned} & V_{c c}=5.0 \mathrm{~V} \\ & V_{c c}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 270 \\ & 100 \end{aligned}$ | $\begin{aligned} & \hline 500 \\ & 220 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {ACC }}$ | Access Time from Address Input | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{c C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 350 \\ & 130 \end{aligned}$ | $\begin{aligned} & 650 \\ & 280 \end{aligned}$ | ns |
| $t_{\text {SA }}$ | Address Setup Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 150 \\ & 60 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {HA }}$ | Address Hold Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 60 \\ & 40 \end{aligned}$ |  |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {ME }}$ | Memory Enable Pulse Width | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 400 \\ & 150 \end{aligned}$ | $\begin{gathered} 250 \\ 90 \end{gathered}$ |  | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{t}_{\text {ME }}$ | Memory Enable Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{c \mathrm{C}}=10 \mathrm{~V} \\ & \hline \end{aligned}$ | $\begin{aligned} & 400 \\ & 150 \\ & \hline \end{aligned}$ | $\begin{gathered} 200 \\ 70 \\ \hline \end{gathered}$ |  | $\begin{array}{r} \mathrm{ns} \\ \mathrm{~ns} \\ \hline \end{array}$ |

## AC Electrical Characteristics (Contid.)

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {SR }}$ | Write Enable Setup Time | $\mathrm{V}_{C C}=5.0 \mathrm{~V}$ | 0 |  |  | ns |
|  | for a Read | $\mathrm{V}_{C C}=10 \mathrm{~V}$ | 0 |  |  | ns |
| tws | Write Enable Setup Time | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  |  | $t_{\text {ME }}$ | ns |
|  | for a Write | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ |  |  | $t_{M E}$ | ns |
| $t_{\text {WE }}$ | Write Enable Pulse Width | $V_{C C}=5.0 \mathrm{~V}, \mathrm{t}_{\mathrm{Ws}}=0$ | 300 | 160 |  | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{t}_{\mathrm{WS}}=0$ | 100 | 60 |  | ns |
| $t_{\text {HD }}$ | Data Input Hold Time | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ | 50 |  |  | ns |
|  |  | $V_{C C}=10 \mathrm{~V}$ | 25 |  |  | ns |
| $t_{\text {SD }}$ | Data Input Setup | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ | 50 |  |  | ns |
|  |  | $V_{C C}=10 \mathrm{~V}$ | 25 |  |  | ns |
| $\mathrm{t}_{\mathrm{IH}}, \mathrm{t}_{\mathrm{OH}}$ | Propagation Delay from a Logical | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=5.0 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}$ |  | 180 | 300 | ns |
|  | " 1 " or Logical "0" to the High Impedance State from Memory Enable | $V_{C C}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=5.0 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}$ |  | -85 | 120 | ns |
| $\mathrm{t}_{\mathrm{IH}}, \mathrm{t}_{\mathrm{OH}}$ | Propagation Delay from a Logical | $\mathrm{V}_{C C}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=5.0 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}$ |  | 180 | 300 | ns |
|  | " 1 " or Logical " 0 " to the High Impedance State from Write Enable | $V_{C C}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=5.0 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}$ |  | 85 | 120 | ns |
| $\mathrm{C}_{\text {IN }}$ | Input Capacity | Any Input (Note 2) |  | 5.0 |  | pF |
| $\mathrm{C}_{\text {OUT }}$ | Output Capacity | Any Output (Note 2) |  | 6.5 |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacity | (Note 3) |  | 230 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note, AN-90.
AC Electrical Characteristics (Guaranteed across the specified temperature range, $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ ) (cont'd)

| Parameter | Conditions | $\begin{gathered} \text { MM54C89 } \\ \mathrm{T}_{\mathrm{A}}=55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \end{gathered}$ |  | $\begin{gathered} \text { MM74C89 } \\ \mathrm{T}_{\mathrm{A}}=-45^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \end{gathered}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Max. |  |
| $t_{P D}$ | $\begin{aligned} & V_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & \hline 700 \\ & 310 \\ & 250 \end{aligned}$ |  | $\begin{aligned} & 600 \\ & 265 \\ & 210 \end{aligned}$ |  |
| $t_{\text {ACC }}$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 910 \\ & 400 \\ & 320 \end{aligned}$ |  | $\begin{aligned} & 780 \\ & 345 \\ & 270 \end{aligned}$ | ns <br> ns <br> ns |
| $t_{\text {SA }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=15 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 210 \\ 90 \\ 70 \end{gathered}$ |  | $\begin{aligned} & 180 \\ & 80 \\ & 60 \end{aligned}$ |  | ns <br> ns <br> ns |
| $t_{H A}$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 80 \\ & 55 \\ & 45 \end{aligned}$ |  | $\begin{aligned} & 70 \\ & 50 \\ & 40 \end{aligned}$ |  |  |
| $t_{\text {ME }}$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 560 \\ & 210 \\ & 170 \end{aligned}$ |  | $\begin{aligned} & 480 \\ & 180 \\ & 150 \end{aligned}$ |  |  |
| $t_{\text {ME }}$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 560 \\ & 210 \\ & 170 \end{aligned}$ |  | $\begin{aligned} & 480 \\ & 180 \\ & 150 \end{aligned}$ |  | ns ns ns |
| $t_{\text {WE }}$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 420 \\ & 140 \\ & 110 \end{aligned}$ |  | $\begin{aligned} & 360 \\ & 120 \\ & 100 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ ns |
| $t_{H D}$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 70 \\ & 35 \\ & 30 \end{aligned}$ |  | $\begin{aligned} & 60 \\ & 30 \\ & 25 \end{aligned}$ | - |  |
| $t_{\text {SA }}$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \\ & V_{C C}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 70 \\ & 35 \\ & 30 \end{aligned}$ |  | $\begin{aligned} & 60 \\ & 30 \\ & 25 \end{aligned}$ |  |  |
| $\mathrm{t}_{\mathrm{IH}}, \mathrm{t}_{\mathrm{OH}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=5.0 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega \end{aligned}$ |  | $\begin{aligned} & 420 \\ & 170 \\ & 135 \\ & \hline \end{aligned}$ |  | $\begin{aligned} & 360 \\ & 145 \\ & 115 \end{aligned}$ |  |

Truth Table

| ME | WE | OPERATION | CONDITION OF OUTPUTS |
| :--- | :--- | :--- | :--- |
| L | L | Write | TRI-STATE ${ }^{\circledR}$ |
| L | H | Read | Complement of Selected Word |
| H | L | Inhibit, Storage | TRI-STATE ${ }^{\circledR}$ |
| $H$ | $H$ | Inhibit, Storage | TRI-STATE ${ }^{\circledR}$ |

## AC Test Circuit


$\mathbf{t}_{1} \mathrm{H}$


## Switching Time Waveforms



Read Modify Write Cycle


MM54C200／MM74C200 256－Bit TRI－STATE ${ }^{\circledR}$ Random Access Read／Write Memory

## General Description

The MM54C200／MM74C200 is a 256 －bit random access read／write memory．Inputs consist of eight address lines， and three chip enables．The eight binary address inputs are decoded internally to select each of the 256 locations． The internal address register，latches，and address in－ formation are on the positive to negative edge of $\overline{\mathrm{CE}}_{3}$ ． The TRI－STATE ${ }^{\circledR}$ data output line，working in conjunction with $\overline{\mathrm{CE}}_{1}$ or $\overline{\mathrm{CE}}_{2}$ inputs，provides for easy memory ex－ pansion．
Address Operation：Address inputs must be stable $t_{S A}$ prior to the positive to negative transition of $\overline{\mathrm{CE}}_{3}$ ．It is therefore unnecessary to hold address information stable for more than $t_{\text {HA }}$ after the memory is enabled （positive to negative transition）．
Note：The timing is different from the DM74200 in that a positive to negative transition of the $\overline{\mathrm{CE}}_{3}$ must occur for the memory to be selected．
Read Operation：The data is read out by selecting the proper address and bringing $\overline{\mathrm{CE}}_{3}$ low and $\overline{\mathrm{WE}}$ high．

Holding either $\overline{\mathrm{CE}}_{1}, \overline{\mathrm{CE}}_{2}$ ，or $\overline{\mathrm{CE}}_{3}$ at a high level forces the output into TRI－STATE．When used in bus－organized sys－ tems，$\overline{\mathrm{CE}}_{1}$ ，or $\overline{\mathrm{CE}}_{2}$ ，a TRI－STATE control provides for fast access times by not totally disabling the chip．

Write Operation：Data is written into the memory with $\overline{\mathrm{CE}}_{3}$ low and $\overline{\mathrm{WE}}$ low．The state of $\overline{\mathrm{CE}}_{1}$ or $\overline{\mathrm{CE}}_{2}$ has no effect on the write cycle．The output assumes TRI－STATE with $\overline{W E}$ low．

## Features

－Wide supply voltage range 3.0 V to 15 V
－Guaranteed noise margin 1.0 V
－High noise immunity $0.45 \mathrm{~V}_{\mathrm{CC}}$（typ．）
－TTL compatibility
－Low power driving standard TTL 500 nW（typ．）
－Internal address register

## Logic and Connection Diagrams




Order Number MM54C200D or MM74C200D
See Package 3
Order Number MM74C200N See Package 15

Voltage at Any Pin
Operating Temperature Range
MM54C200
MM74C200
Storage Temperature Range
Package Dissipation
Operating $\mathrm{V}_{\mathrm{CC}}$ Range
Absolute Maximum $V_{C C}$
Lead Temperature (Soldering, 10 seconds)
-0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
3.0 V to 15 V

18 V
$300^{\circ} \mathrm{C}$

DC Electrical Characteristics Min./max. limits apply across temperature range, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMOS to CMOS |  |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 8.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {IN(0) }}$ | Logical "0' Input Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=-10 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 9.0 \end{aligned}$ |  |  | V |
| $V_{\text {OUT(0) }}$ | Logical "0" Output Voltage | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \\ & V_{C C}=10 \mathrm{~V}, I_{O}=+10 \mu \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $1 \mathrm{IN}(1)$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.005 | 1.0 | $\mu \mathrm{A}$ |
| $I_{\text {IN(0) }}$ | Logical " 0 " Input Current | $V_{C C}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| ICC | Supply Current | $V_{C C}=15 \mathrm{~V}$ |  | 0.10 | 600 | $\mu \mathrm{A}$ |
| CMOS/TTL Interface |  |  |  |  |  |  |
| $V_{\text {IN(1) }}$ | Logical "1" Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V} \end{array}$ | $\begin{aligned} & V_{C C}-1.5 \\ & V_{C C}-1.5 \end{aligned}$ |  |  | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{V}_{\text {IN(0) }}$ | Logical " 0 " Input Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V} \\ 74 \mathrm{C} & V_{C C}=4.75 \mathrm{~V} \end{array}$ |  |  | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $V_{\text {OUT(1) }}$ | Logical "1" Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & \mathrm{~V}_{C C}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-1.6 \mathrm{~mA} \\ 74 \mathrm{C} & \mathrm{~V}_{\mathrm{CC}}=4.75, \mathrm{I}_{\mathrm{O}}=-1.6 \mathrm{~mA} \end{array}$ | $\begin{aligned} & 2.4 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $V_{\text {OUT(0) }}$ | Logical " 0 " Output Voltage | $\begin{array}{ll} 54 \mathrm{C} & V_{C C}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=1.6 \mathrm{~mA} \\ 74 \mathrm{C} & V_{C C}=4.75, \mathrm{I}_{\mathrm{O}}=1.6 \mathrm{~mA} \end{array}$ |  |  | 0.4 | V |

Output Drive (See 54C/74C Family Characteristics Data Sheet) (Short Circuit Current)

| ISOURCE | Output Source Current (P-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | $\begin{aligned} & -4.0 \\ & -1.8 \end{aligned}$ | -6.0 | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Isource | Output Source Current (P-Channel) | $\begin{aligned} & V_{C C}=10 \mathrm{~V}, \quad V_{\text {OUT }}=0 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ | $\begin{gathered} -16.0 \\ -1.5 \end{gathered}$ | -25 | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current ( N -Channel) | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | 5.0 | 8.0 | mA |
| $\mathrm{I}_{\text {SINK }}$ | Output Sink Current (N-Channel) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~T}_{\mathrm{A}}={ }^{\circ} \mathrm{C} \end{aligned}$ | 20 | 30 | mA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

| Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {Acc }}$ Access Time from Address | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 450 \\ & 200 \end{aligned}$ | $\begin{aligned} & 900 \\ & 400 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{pd}}$ Propagation Delay from $\overline{\mathrm{CE}}_{3}$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 360 \\ & 120 \end{aligned}$ | $\begin{aligned} & 700 \\ & 300 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {pCE1 }}$ Propagation Delay from $\overline{\mathrm{CE}}_{1}$ or $\overline{\mathrm{CE}}_{2}$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 250 \\ 85 \end{gathered}$ | $\begin{aligned} & 700 \\ & 200 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {SA }}$ Address Setup Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 200 \\ & 100 \end{aligned}$ | $\begin{aligned} & 80 \\ & 30 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{HA}}$ Address Hold Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{aligned} & 15 \\ & 5.0 \end{aligned}$ |  | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| t $\overline{\text { WE }}$ Write Enable Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 300 \\ & 150 \end{aligned}$ | $\begin{aligned} & 160 \\ & 70 \end{aligned}$ |  | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{t}_{\mathrm{CE}} \quad \overline{\mathrm{CE}}_{3}$ Pulse Widths | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 400 \\ & 160 \end{aligned}$ | $\begin{gathered} 200 \\ 80 \end{gathered}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ Input Capacity | Any Input (Note 2) |  | 5.0 |  | pF |
| Cout Output Capacity in TRI-STATE ${ }^{\text {® }}$ | (Note 2) |  | 9.0 |  | pF |
| $\mathrm{C}_{\text {PD }}$ Power Dissipation Capacity | (Note 3) |  | 400 |  | pF |

$\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$

| Parameter |  | Conditions | $\begin{array}{c\|} \hline \text { MM54C200 } \\ T_{A}=-55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \\ \hline \end{array}$ |  | $\begin{gathered} \text { MM74C200 } \\ T_{\mathrm{A}}=-45^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \end{gathered}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Max. |  |
| $t_{\text {ACC }}$ | Access Time from Address |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} \hline 1200 \\ 520 \end{gathered}$ |  | $\begin{gathered} 1100 \\ 480 \end{gathered}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Delay from $\overline{\mathrm{CE}}_{3}$ | $\begin{aligned} & V_{c C}=5.0 \mathrm{~V} \\ & V_{c C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 950 \\ & 400 \end{aligned}$ |  | $\begin{aligned} & 850 \\ & 360 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{pd} \mathrm{CE} 1}$ | Propagation Delay from $\overline{\mathrm{CE}}_{1}$ or $\overline{\mathrm{CE}}_{2}$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 650 \\ & 300 \end{aligned}$ |  | $\begin{aligned} & 600 \\ & 275 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {SA }}$ | Address Setup Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 250 \\ & 120 \end{aligned}$ |  | $\begin{aligned} & 250 \\ & 120 \end{aligned}$ |  | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {HA }}$ | Address Hold Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 100 \\ & 50 \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 50 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {WE }}$ | $\overline{\text { Write Enable Pulse Width }}$ | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 450 \\ & 225 \end{aligned}$ |  | $\begin{aligned} & 400 \\ & 200 \end{aligned}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| ${ }^{\text {t }}$ CE | Disable Pulse Width | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 500 \\ & 250 \end{aligned}$ |  | 460 230 |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{HD}}$ | Data Hold Time | $\begin{aligned} & V_{C C}=5.0 \mathrm{~V} \\ & V_{C C}=10 \mathrm{~V} \end{aligned}$ | $\begin{array}{r} 50 \\ 25 \\ \hline \end{array}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ |  | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{P D}$ determines the no load $A C$ power consumption of any $C M O S$ device. For complete explanation see $54 \mathrm{C} / 74 \mathrm{C}$ Family Characteristics application note, AN-90.


Note: Used for fast access time in bused systems.

## MM54C910/MM74C910 256 Bit TRI-STATE ${ }^{\circledR}$ Random Access Read/Write Memory

## General Description

The MM54C910/MM74C910 is a 64 word by 4 bit random access memory. Inputs consist of six address lines, four data input lines, a $\overline{W E}$, and a $\overline{M E}$ line. The six address. lines are internally decoded to select one of 64 word locations. An internal address register latches the address information on the positive to negative transition of ME. The TRI-STATE ${ }^{\circledR}$ outputs allow for easy memory expansion.

Address Operation: Address inputs must be stable ( $\mathrm{t}_{\mathrm{SA}}$ ) prior to the positive to negative transition of $\overline{M E}$, and $\left(\mathrm{t}_{\mathrm{HA}}\right)$ after the positive to negative transition of $\overline{M E}$. The address register holds the information and stable address inputs are not needed at any other time.

Write Operation: Data is written into memory at the selected address if $\overline{\mathrm{WE}}$ goes low while $\overline{\mathrm{ME}}$ is low. $\overline{\mathrm{WE}}$ must be held low for twe and data must remain stable $t_{H D}$ after $\overline{W E}$ returns high.
Read Operation: Data is nondestructively read from a memory location by an address operation with $\overline{W E}$ held high.
TRI-STATE is a registered trademark of National Semiconductor Corp.

Outputs are in the TRI-STATE ${ }^{\circledR}$ ( $\mathrm{Hi}-\mathrm{Z}$ ) condition when the device is writing or disabled.

## Features

- Supply voltage range
3.0 V to 5.5 V
- High noise immunity
$0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.)
- TTL compatible fan out

1 TTL load

- Input address register

■ Low power consumption
250 nW/package (typ.) (chip enabled or disabled)
. Fast access time
250 ns (typ.) at 5.0 V
a TRI-STATE outputs

- High voltage inputs

Logic and Connection Diagram



Dual-In-Line Package

$\begin{array}{lr}\text { Absolute Maximum Ratings (Note 1) } \\ \text { Voltage at any Output Pin } & -0.3 \mathrm{~V} \text { to } \mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V} \\ \text { Voltage at any Input Pin } & -0.3 \mathrm{~V}+0+15 \mathrm{~V} \\ \text { Package Dissipation } & 500 \mathrm{~mW} \\ \text { Operating } \mathrm{V}_{\mathrm{CC}} \text { Range } & 3.0 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\ \text { Standby } \mathrm{V}_{\mathrm{cc}} \text { Range } & 1.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\ \text { Absolute Maximum } \mathrm{V}_{\mathrm{CC}} & 6.0 \mathrm{~V} \\ \text { Lead Temperature (Soldering, } 10 \text { seconds( } & 300^{\circ} \mathrm{C}\end{array}$
DC Electrical Characteristics
Min./max. limits apply across the temperature and power supply range indicated

| Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {IN(1) }}$ Logical "1" Input Voltage | Full Range | $\mathrm{V}_{C C}-1.5$ |  |  | V |
| $\mathrm{V}_{\operatorname{IN}(0)}$ Logical "0', Input Voltage | Full Range |  |  | 0.8 | V |
| $I_{\text {IN(1) }}$ Logical "1" Input Current | $\begin{aligned} & V_{I N}=15 \mathrm{~V} \\ & V_{I N}=5.0 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.005 \\ & 0.005 \end{aligned}$ | $\begin{aligned} & 2.0 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |
| $\mathrm{I}_{\mathrm{IN}(0)}$ Logical "0' Input Current | $\mathrm{V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ | -1.0 | -0.005 |  | $\mu \mathrm{A}$ |
| $V_{\text {OUT(1) }}$ Logical "1" Output Voltage | $\begin{aligned} & \mathrm{I}_{\mathrm{O}}=-150 \mu \mathrm{~A} \\ & \mathrm{I}_{\mathrm{O}}=-400 \mu \mathrm{~A} \end{aligned}$ | $\begin{gathered} \mathrm{V}_{\mathrm{CC}}-0.5 \\ 2.4 \end{gathered}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Vout(0) Logical "0" Output Voltage | $\mathrm{I}_{\mathrm{O}}=1.6 \mathrm{~mA}$ |  |  | 0.4 | V |
| Output Current in High Impedance State | $\begin{aligned} & V_{O}=5.0 \mathrm{~V} \\ & V_{O}=0 \mathrm{~V} \end{aligned}$ | -1.0 | $\begin{array}{r} 0.005 \\ -0.005 \end{array}$ | 1.0 | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |
| ICC Supply Current | $\mathrm{V}_{C C}=5.0 \mathrm{~V}$ |  | 5.0 | 300 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$


AC Electrical Characteristics (cont'd) $C_{L}=50 \mathrm{pF}$

| Parameter |  | $\begin{gathered} \text { MM54C910 } \\ T_{A}=-55^{\circ} \text { to }+125^{\circ} \mathrm{C} \\ V_{C C}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{gathered}$ |  | $\begin{gathered} \text { MM74C910 } \\ T_{A}=-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \\ \mathrm{~V}_{\mathrm{CC}}=4.75 \mathrm{~V} \text { to } 5.25 \mathrm{~V} \end{gathered}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Max. |  |
| $\mathrm{t}_{\text {ACC }}$ | Access Time from Address |  | 860 |  | 700 | ns |
| $\mathrm{t}_{\mathrm{pd} 1}, \mathrm{t}_{\mathrm{pd} 0}$ | Propagation Delay from $\overline{M E}$ |  | 660 |  | 540 | ns |
| $\mathrm{t}_{\text {SA }}$ | Address Input Set-Up Time | 200 |  | 160 |  | ns |
| ${ }^{\text {tha }}$ | Address Input Hold Time | 20 |  | 20 |  | ns |
| $t_{\text {ME }}$ | Memory Enable Pulse Width | 280 |  | 260 |  | ns |
| $t_{\text {ME }}$ | Memory Enable Pulse Width | 750 |  | 600 |  | ns |
| ${ }^{\text {t }}$ S | Data Input Set-Up Time | 0 |  | 0 |  | ns |
| $t_{\text {HD }}$ | Data Input Hold Time | 50 |  | 50 |  | ns |
| $\mathrm{t}_{\underline{W E}}$ | $\overline{\text { Write Enable Pulse Width }}$ | 200 |  | 180 |  | ns |
| $\mathrm{t}_{1 \mathrm{H}}, \mathrm{t}_{\mathrm{OH}}$ | Delay to TRI-STATE ${ }^{\text {( }}$ ( ( ${ }^{\text {ate 4) }}$ |  | 200 |  | 200 | ns |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: $\mathrm{C}_{\text {PD }}$ determines the no load AC power consumption for any CMOS device. For complete explanation see 54C/74C Family Characteristics application note AN-90.
Note 4: See AC test circuit for $\mathrm{t}_{1 \mathrm{H}}, \mathrm{t}_{\mathrm{OH}}$.

## Typical Performance Characteristics

Typical Access Time vs Ambient Temperature


| $\overline{\text { ME }}$ | $\overline{\text { WE }}$ | OPERATION | OUTPUTS |
| :---: | :---: | :--- | :--- |
| L | L | Write | TRI-STATE |
| L | H | Read | Data |
| H | L | Inhibit, Store | TRI-STATE |
| $H$ | H | Inhibit, Store | TRI-STATE |

Truth Table

## AC Test Circuit



## Switching Time Waveforms



Note 1: MEMORY ENABCE must be brought high for tME nanoseconds between every address change, Note 2. $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{t}}=20 \mathrm{~ns}$ for all snputs.

## MM54C920/MM74C920, MM54C921/MM74C921 <br> 1024-Bit Static Silicon Gate CMOS RAMs

## General Description

The MM54C920/MM74C920 $256 \times 4$ random access read/write memory is manufactured using silicon gate CMOS technology. Data output is the same polarity as data input. Internal latches store address inputs CES and data output. This RAM is specifically designed to operate from standard 54/74 TTL power supplies. All inputs and outputs are TTL compatible.

The MM54C921/MM74C921 is identical to the MM54C920/MM74C920, except data inputs are internally connected to data outputs; the number of package leads thereby is reduced to 18 .

Complete address decoding as well as 2-chip select functions, $\overline{\mathrm{CEL}}$ and $\overline{\mathrm{CES}}$, and TRI-STATE ${ }^{(i)}$ outputs allow easy expansion with a minimum of external components. Versatility plus high speed and low power make
these RAMs ideal elements for use in microprocessor, minicomputer as well as main frame memory applications.

## Features

- $256 \times 4$-bit organization
- Access time

250 ns max MM74C920, MM74C921
275 ns max MM54C920, MM54C921
300 ns max MM74C920-3, MM74C921-3

- TRI-STATE outputs
- Low power
- On-chip registers
- Single 5V supply
- Data retained with $\mathrm{V}_{\mathrm{CC}}$ as low as 2 V


## Connection Diagrams



## Logic Symbols



The functional description will reference the logic diagram of the MM54C920/MM74C920 shown in Figure 1. Input addresses and $\overline{\mathrm{CES}}$ are clocked into 'the input latches by the falling edge of STROBE. Input set-up and hold times must be observed on these signals (see timing diagrams). The true and complement address information is fed to the row and column decoders which access the selected 4-bit memory word.

The addressed word ( 4 bits) is fed to 4 sense amplifiers through the column decoders. The information from the sense amplifiers is latched into the output register when $\overline{\text { STROBE }}$ rises. The register drives the TRI-STATE ${ }^{\circledR}$ output buffers.

Chip select inputs, $\overline{\mathrm{CEL}}$ and $\overline{\mathrm{CES}}$, have identical functions except that $\overline{\mathrm{CES}}$ (Chip Enable Stored) is clocked into a latch on the falling edge of $\overline{\mathrm{STROBE}} ; \overline{\mathrm{CEL}}$ (Chip Enable Level) is not.

Note that set-up and hold times must be observed on $\overline{\mathrm{CES}}$. Because $\overline{\mathrm{CEL}}$ is not clocked by $\overline{\mathrm{STROBE}}$, it may fall after $\overline{S T R O B E}$ has fallen without affecting access time provided that the tOE requirement is met.

The outputs are in a high impedance state when the chip is not selected ( $\overline{\mathrm{CES}}$ or $\overline{\mathrm{CEL}}$ high) or when writing ( $\overline{W E}$ low). Note that the information stored in the output latches will be changed whenever $\overline{\text { STROBE }}$ falls, regardless of the logic states of $\overline{\mathrm{WE}}, \overline{\mathrm{CEL}}$ or $\overline{\mathrm{CES}}$.

The switching time waveforms in Figures 2, 3 and 4 define the read, write, and output enable/disable parameters respectively.

## Reduced-Voltage Operation

These memories will retain data with reduced $\mathrm{V}_{\mathrm{CC}}$ and hence are useful for battery-backup data storage. Certain precautions must be observed as $V_{C C}$ is reduced: (1) input voltages must remain between the $\mathrm{V}_{\mathrm{CC}}$ and ground of the RAM or supply latch-up can occur, (2) WRITE mode must be avoided, (3) during power-up of $V_{C C}$, $\overline{\text { ST }}$ logic state must be maintained (either GND or $\mathrm{V}_{\mathrm{CC}}$ ) while address control lines stabilize.

## Logic Diagram*



FIGURE 1. MM54C920/MM74C920

[^11]
## Absolute Maximum Ratings（Note 1）

| Supply Voltage，$V_{C C}$ | 7 V |
| :--- | ---: |
| Voltage at Any Pin | -0.3 V to $V_{C C}+0.3 \mathrm{~V}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Package Dissipation | 500 mW |
| Lead Temperature（Soldering， 10 seconds） | $300^{\circ} \mathrm{C}$ |

DC Electrical Characteristics （Note 2）

Operating Conditions

|  | MIN | MAX | UNITS |
| :--- | :--- | :--- | :---: |
| Supply Voltage（VCC） |  |  |  |
| MM54C920，MM54C921 | 4.5 | 5.5 | V |
| MM74C920，MM74C921 | 4.5 | 5.5 | V |
| MM74C920－3，MM74C921－3 | 4.75 | 5.25 | V |
| Ambient Temperature（TA） |  |  |  |
| MM54C920，MM54C921 | -55 | +125 | ${ }^{\circ} \mathrm{C}$ |
| MM74C920，MM74C921 | -40 | +85 | ${ }^{\circ} \mathrm{C}$ |
| MM74C920－3，MM74C921－3 | 0 | +70 | ${ }^{\circ} \mathrm{C}$ |


| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :--- | :--- | :--- | :---: | :---: | :---: | :---: |
| $C_{I N}$ | Input Capacitance | $V_{I N}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}, \mathrm{TA}=25^{\circ} \mathrm{C}$ |  | 4 | 7 | pF |
| $\mathrm{C}_{\mathrm{O}}$ | Output Capacitance | $\mathrm{V}_{I N}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}, \mathrm{TA}=25^{\circ} \mathrm{C}$ |  | 6 | 9 | pF |
| $\mathrm{C}_{\mathrm{I} / \mathrm{O}}$ | Data Input／Output Capacitance | $\mathrm{MM} 54 \mathrm{C} 921 / \mathrm{MM} 74 \mathrm{C} 921$ Only |  | 8 | 12 | pF |

Note 1：＂Absolute Maximum Ratings＂are those values above which the device may be permanently damaged．They do not mean the device may be operated at these values．
Note 2：These limits apply over the entire operating range specified in the＂Operating Conditions＂unless otherwise stated．
Note 3：$\overline{\mathrm{CEL}}=\mathrm{V}_{\mathrm{CC}}-2 \mathrm{~V}$ or $=2 \mathrm{~V}$ ，whichever is greater．
Note 4．Capacitance is guaranteed by periodic testing．

| $\overline{\text { ST }}$ | $\overline{\text { CES* }}$ | $\overline{\text { CEL }}$ | $\overline{\text { WE }}$ | DI* | FUNCTION |
| :---: | :---: | :---: | :---: | :---: | :--- |
| X | X | 1 | X | X | Output in Hi-Z state |
| 0 | 1 | X | X | X | Output in Hi-Z state |
| X | X | X | 0 | X | Output in $\mathrm{Hi}-\mathrm{Z}$ state |
| 0 | 0 | 0 | 0 | 0 | Write "0", output in $\mathrm{Hi}-\mathrm{Z}$ state |
| 0 | 0 | 0 | 0 | 1 | Write " 1 ", output in Hi-Z state |
| 0 | 0 | 0 | 1 | X | Read data, output enabled |

*Set-up and hold times must be met X $=$ don't care

AC Electrical Characteristics (Note 5)

| SYMBOL | PARAMETER | MM54C920, MM54C921 |  | MM74C920, MM74C921 |  | MM74C920-3 <br> MM74C921-3 |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {t }} \mathrm{C}$ | Cycle Time | 290 |  | 255 |  | 330 |  | ns |
| ${ }^{\text {t }}$ ACC | Access Time From Address |  | 275 |  | 250 |  | 325 | ns |
| tacs | Access Time From Strobe |  | 250 |  | 225 |  | 300 | ns |
| tAS | Address Set-Up Time | 25 |  | 25 |  | 25 |  | ns |
| ${ }^{\text {t }} \mathrm{AH}$ | Address Hold Time | 25 |  | 25 |  | 25 |  | ns |
| toe | Output Enable Time |  | 150 |  | 130 |  | 130 | ns |
| tod | Output Disable Time |  | 150 |  | 130 |  | 130 | ns |
| ${ }^{\text {t }} \overline{S T}$ | $\overline{\text { ST Pulse Width ( }}$ ( ${ }^{\text {a }}$ ( ${ }^{\text {ative) }}$ | 150 |  | 130 |  | 165 |  | ns |
| ${ }^{\text {tST}}$ | ST Pulse Width (Positive) | 140 |  | 125 |  | 165 |  | ns |
| tWP | Write Pulse Width (Negative) | 150 |  | 130 |  | 165 |  | ns |
| ${ }^{\text {t D S }}$ | Data Set-Up Time | 100 |  | 90 |  | 90 |  | ns |
| tDH | Data Hold Time | 60 |  | 60 |  | 60 |  | ns |

Note 5: These limits apply over the operating range specified in the "Operating Conditions" with trise $=\mathrm{t}_{\mathrm{t}}$ FALL $=5 \mathrm{~ns}$, load $=1 \mathrm{TTL}$ gate + 50 pF .

## Switching Time Waveforms



FIGURE 2. Read Cycle $\left(\overline{W E}=V_{I H}\right)$


FIGURE 4. Output Enable/Disable


Minimum Write Pulse Width vs Ambient Temperature


Data In Hold Time vs
Ambient Temperature


Address Hold Time vs
Ambient Temperature


Access Time vs Power Supply Voltage


Data-In Setup Time vs Ambient Temperature


Minimum ST Pulse Width (Positive) vs Ambient Temperature


Address Setup Time vs Ambient Temperature


## MM54C929/MM74C929, MM54C930/MM74C930 1024-Bit Static Silicon Gate CMOS RAMs

## General Description

The MM54C929/MM74C929 and the MM54C930/ MM74C930 $1024 \times 1$ random access read/write memories are manufactured using silicon-gate CMOS technology. These RAMs are specifically designed to operate from standard 54/74 TTL power supplies; all inputs and outputs are TTL compatible. Data output is the same polarity as data input. Internal latches store the address inputs and data output. Chip select input $\overline{\mathrm{CS} 1}$ serves as a chip strobe, controlling address and data latching. The Data-In and Data-Out terminals can be tied together for common I/O applications. Complete address decoding, 3 -chip select functions (MM54C930/MM74C930) and TRI-STATE ${ }^{\circledR}$ output allow easy memory expansion and organization. The MM54C929/MM74C929 differs from the MM54C930/MM74C930 only in that CS1, CS2 and $\overline{\mathrm{CS} 3}$ are internally connected together, providing a single chip-select input $\overline{\mathrm{CS}}$.

Versatility, high speed, and low power make these RAMs ideal elements for use in many microprocessor, minicomputer and main-frame-memory applications.

## Features

- Fast access-250 ns max
- TRI-STATE outputs
- Low power-10 $\mu \mathrm{A}$ max standby
- On-chip registers
- Single 5V supply
- Inputs and output TTL compatible
- Data retained with $V_{C C}$ as low as 2 V
- Can be operated common I/O


## Connection Diagrams



Dual-In-Line Package


## Logic Symbols



## Functional Description

Address inputs are clocked into the input latches by the falling edge of chip strobe $\overline{\mathrm{CS} 1}$; set-up and hold times must be observed on these input signals (see timing diagram). The true and complement address information is fed to the row and column decoders which select one of the 1024-bit locations. The addressed bit is fed, via a sense amplifier, to the output register and TRI-STATE® buffer. The information is latched into the output register on the rising edge of chip strobe $\overline{\mathrm{CS}} 1$. The output is in a high impedance state when the chip is not selected ( $\overline{\mathrm{CS} 2}$ or $\overline{\mathrm{CS} 3}$ high) or when writing ( $\overline{\mathrm{WE}}$ low). Output buffer control is independent of chip strobe $\overline{\mathrm{CS} 1}$.

## Reduced-Voltage Operation

These memories will retain data with reduced $V_{C C}$ and hence are useful for battery-backup data storage. Certain precautions must be observed as $\mathrm{V}_{\mathrm{CC}}$ is reduced: (1) input voltages must remain between the $V_{C C}$ and ground of the RAM or supply latch-up can occur, (2) WRITE mode must be avoided, (3) during power-up of $\mathrm{V}_{\mathrm{CC}}$, strobe ( $\overline{\mathrm{CS}}$ for the MM74C929 and $\overline{\mathrm{CS} 1}$ for the MM74C930) logic state must be maintained (either GND or $\mathrm{V}_{\mathrm{CC}}$ l while address control lines stabilize.

## Logic Diagram*


*The MM74C930 has 3 chip selects $\overline{\mathrm{CS} 1}, \overline{\mathrm{CS} 2}$ and $\overline{\mathrm{CS} 3}$. The MM74C929 has these internally connected together providing a single chip select input $\overline{\mathrm{CS}}$.

FIGURE 1

## Absolute Maximum Ratings

Supply Voltage, $\mathrm{V}_{\mathrm{CC}}$
Voltage at Any Pin
Storage Temperature Range
Operating Temperature Range
MM54C929, MM54C930
MM74C929, MM74C930
MM74C929-3, MM74C930-3
Package Dissipation
Lead Temperature (Soldering 10 seconds)
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ 500 mW $300^{\circ} \mathrm{C}$
DC Electrical Characteristics $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V} \pm 10 \%, \mathrm{~T}_{\mathrm{A}}=$ Operating Range, unless otherwise noted

| SYMBOL | PARAMETER | CONDITIONS | MM54C929, MM54C930 |  | MM74C929, MM74C930 |  | MM74C929-3, <br> MM74C930-3 <br> (NOTE 1) |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | MAX | MIN | MAX |  |
| $\mathrm{V}_{\text {IH }}$ | Logical " 1 " Input Voltage |  | $\mathrm{V}_{\mathrm{CC}}-2.0$ | $V_{\text {CC }}$ | $\mathrm{V}_{\mathrm{CC}}-2.0$ | $\mathrm{V}_{\mathrm{CC}}$ | $\mathrm{V}_{\mathrm{CC}}{ }^{-2.0}$ | $V_{\text {CC }}$ | V |
| VIL | Logical "0" Input Voltage |  | 0 | 0.8 | 0 | 0.8 | 0 | 0.8 | V |
| VOH | Logical "1" Output Voltage | $1 \mathrm{OH}=1 \mathrm{~mA}$ | 2.4 |  | 2.4 |  | 2.4 |  | $\checkmark$ |
| $\mathrm{VOH}_{2}$ | Logical "1" Output Voltage | IOUT = 0 | $V_{C C}{ }^{-0.1}$ |  | $V_{C C}{ }^{-0.1}$ |  | $V_{C C}{ }^{-0.1}$ |  | $\checkmark$ |
| VOL1 | Logical "0" Output Voltage | ${ }^{1} \mathrm{OL}=2.0 \mathrm{~mA}$ |  | 0.4 |  | 0.4 |  | 0.4 | V |
| VOL2 | Logical "0' Output Voltage | IOUT $=0$ |  | 0.01 |  | 0.01 | . | 0.01 | $\checkmark$ |
| IIL | Input Leakage | $\mathrm{OV} \leq \mathrm{V}_{\text {IN }} \leq \mathrm{V}_{\mathrm{CC}}$ | -1.0 | 1.0 | -1.0 | 1.0 | -1.0 | 1.0 | $\mu \mathrm{A}$ |
| 10 | Output Leakage | $\mathrm{OV} \leq \mathrm{V}_{\mathrm{O}} \leq \mathrm{V}_{\mathrm{CC}}$. (Note 2) | -1.0 | 1.0 | -1.0 | 1.0 | -1.0 | 1.0 | $\mu \mathrm{A}$ |
| ${ }^{\text {ICC }}$ | Supply Leakage Current | $V_{\text {IN }}=V_{C C}, V_{O}=0 V$ |  | 20 |  | 10 |  | 100 | $\mu \mathrm{A}$ |
| $V_{\text {DR }}$ | $V_{C C}$ for Data Retention | (Note 3) | 2.0 |  | 2.0 |  | 2.0 |  | V |
| IDR | ICC for Data Retention | $V_{C C}=2 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C},($ Note 2$)$ | $\checkmark$ | $\begin{aligned} & 0.01 \\ & \text { (typ) } \end{aligned}$ |  | $\begin{aligned} & 0.01 \\ & \text { (typ) } \end{aligned}$ |  | $\begin{gathered} 0.1 \\ \text { (typ) } \end{gathered}$ | $\mu \mathrm{A}$ |

Note 1: $V_{C C}=5 \mathrm{~V} \pm 5 \%$.
Note 2: $\overline{\mathrm{CS} 2}=\overline{\mathrm{CS} 3}=\mathrm{V}_{\mathrm{CC}}$ or $\overline{\mathrm{CS}}=\mathrm{V}_{\mathrm{CC}}$.
Note 3: $\overline{\mathrm{CS} 2}$ or $\overline{\mathrm{CS} 3}$ or $\overline{\mathrm{CS}}=\mathrm{V} C C-2 \mathrm{~V}$ or $=2 \mathrm{~V}$, whichever is greater.
AC Electrical Characteristics $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V} \pm 10 \%, \mathrm{~T}_{\mathrm{A}}=$ Operating Range, unless otherwise noted

| TTL Interface ( $\mathrm{V}_{\text {IH }}=\mathrm{V}_{\text {CC }}-2 \mathrm{~V}, \mathrm{~V}_{\text {IL }}=0.8 \mathrm{~V}$, Input $\mathrm{t}_{\mathrm{RISE}}=\mathrm{t}_{\mathrm{FALL}}=5 \mathrm{~ns}$, Load $=1 \mathrm{TTL}$ Gate $\left.+50 \mathrm{pF}\right)$ |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SYMBOL | PARAMETER | MM54C929, MM54C930 |  | MM74C929, MM74C930 |  | MM74C929-3, <br> MM74C930-3 <br> (NOTE 1) |  | UNITS |
|  |  | MIN | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {t }} \mathrm{C}$ | Cycle Time | 290 |  | 255 |  | 330 |  | ns |
| ${ }^{\text {t }}$ ACC | Access Time From Address |  | 265 |  | 240 |  | 315 | ns |
| ${ }^{\text {t }}$ ACS, ${ }^{\text {taCS }} 1$ | Access Time From $\overline{\mathrm{CS}}, \overline{\mathrm{CS} 1}$ |  | 250 |  | 225 |  | 300 | ns |
| ${ }^{t} A S$ | Address Set-Up Time | 15 |  | 15 |  | 15 |  | ns |
| ${ }^{\text {t }} \mathrm{AH}$ | Address Hold Time | 50 |  | 50 |  | 50 |  | ns |
| toe | Output Enable Time |  | 150 |  | 130 |  | 130 | ns |
| tOD | Output Disable Time |  | 150 |  | 130 |  | 130 | ns |
| $\begin{aligned} & \mathrm{t} \overline{\mathrm{CS}}, \mathrm{t} \overline{\mathrm{CS} 1} \\ & \text { (Note 4) } \end{aligned}$ | $\overline{\mathrm{CS}}, \overline{\mathrm{CS} 1}$ Pulse Width (Negative) | 150 |  | 130 |  | 165 |  | ns |
| ${ }^{\text {t CS, }}$, CS 1 | $\overline{\mathrm{CS}}, \overline{\mathrm{CS} 1}$ Pulse Width (Positive) | 140 |  | 125 |  | 165 |  | ns |
| tWP | Write Pulse Width (Negative) | 150 |  | 130 |  | 165 |  | ns |
| ${ }^{\text {t }}$ S | Data Set-Up Time, (Note 5) | 150 |  | 140 |  | 140 |  | ns |
| tDH | -Data Hold Time, (Note 5) | 0 |  | 0 |  | 0 |  | ns |

Note 4: Greater than minimum $\overline{C S}$ pulse width must be used when reading data from the MM54C929/MM74C929 to ensure that outpùt TRISTATING does not occur before data becomes valid. Writing has no such limitation.
Note 5: tDS and tDH are referenced to the low-to-high transition of $\overline{\operatorname{CS1} 1}$ or $\overline{\mathrm{CS} 2}$ or $\overline{\mathrm{CS3}}$ or $\overline{W E}$, whichever switches first, for the MM54C930/ MM74C930 and are referenced to the $\overline{C S}$ or $\overline{W E}$ low-to-high transition, whichever switches first, for the MM54C929/MM74C929.

Capacitance（Note 6）

| SYMBOL | PARAMETER | CONDITIONS | MIN | MAX | UNITS |
| :---: | :--- | :--- | :---: | :---: | :---: |
| $C_{I N}$ | Input Capacitance | $V_{I N}=0, f=1 \mathrm{MHz}, \mathrm{T}_{A}=25^{\circ} \mathrm{C}$ | 4 | 7 | pF |
| $\mathrm{C}_{\mathrm{O}}$ | Output Capacitance | $\mathrm{V}_{\mathrm{IN}}=0, \mathrm{f}=1 \mathrm{MHz}, \mathrm{T}_{A}=25^{\circ} \mathrm{C}$ | 6 | 9 | pF |
| $\mathrm{C}_{\overline{\mathrm{CS}}}$ | Chip Select Capacitance | MM54C929／MM74C929，MM74C929－3 | 8 | 12 | pF |

Note 6：Capacitance maximum is guaranteed by periodic testing．

## Truth Tables

MM54C929／MM74C929

| $\overline{\mathrm{CS}}$ | $\overline{\mathrm{WE}}$ | DI | FUNCTION |
| :---: | :---: | :---: | :--- |
| 1 | X | X | Output in Hi－Z State |
| X | 0 | X | Output in Hi－Z State |
| 0 | 0 | 0 | Write＂ $0,{ }^{\prime \prime}$＇Output in Hi－Z State |
| 0 | 0 | 1 | Write＇＂1，＂Output in Hi－Z State |
| 0 | 1 | X | Read Data，Output Enabled |

X＝Don＇t care

MM54C930／MM74C930

| $\overline{\text { CS1 }}$ | $\overline{\text { CS2 }}$ | $\overline{\text { CS3 }}$ | $\overline{\text { WE }}$ | DI | FUNCTION |
| :---: | :---: | :---: | :---: | :---: | :--- |
| X | 1 | X | X | X | Output in Hi－Z State |
| X | X | 1 | X | X | Output in Hi－Z State |
| X | X | X | 0 | X | Output in Hi－Z State |
| 0 | 0 | 0 | 0 | 0 | Write＂ $0, "$ Output in Hi－Z State |
| 0 | 0 | 0 | 0 | 1 | Write＂1，＂Output in Hi－Z State |
| 0 | 0 | 0 | 1 | X | Read Data，Output Enabled |

## Switching Time Waveforms


＊Greater than minimum $\overline{\mathrm{CS}}$ pulse width must be used when reading data from the MM54C929／MM74C929 to ensure that output TRI－STATING does not occur before data becomes valid．Writing has no such limitation，（Figure 4a）．

FIGURE 2a．MM54C929／MM74C929 Read Cycle


FIGURE 2b．MM54C930／MM74C930 Read Cycle

Switching Time Waveforms (Continued)

 FIGURE 3b. MM54C930/MM74C930 Write Cycle


FIGURE 4a. MM54C929/MM74C929


FIGURE 4b. MM54C930/MM74C930


Minimum Write Pulse Width vs Ambient Temperature


Data-In Hold Time vs
Ambient Temperature


Address Hold Time vs Ambient Temperature


Access Time vs Power Supply Voltage


Data-In Set-Up Time vs Ambient Temperature


Minimum $\overline{\text { CSI }}$ Pulse Width
(Positive) vs Ambient Temperature


Address Set-Up Time vs Ambient Temperature


Test Limit MM54C929, MM54C930


Test Limit MM74C929, MM74C930




Output Sink Current vs Output Voltage


## MM54C989／MM74C989 64－Bit（ $16 \times 4$ ）TRI－STATE ${ }^{\circledR}$ RAM

## General Description

The MM54C989／MM74C989 is a 16 －word by 4 －bit random access read／write memory．Inputs to the memory consist of 4 address lines， 4 data input lines，a write enable line and a memory enable line．The 4 binary address inputs are decoded internally to select each of the 16 possible word locations．An internal address register latches the address information on the positive to negative transition of the memory enable input．The 4 TRI－STATE data output lines working in conjunction with the memory enable input provides for easy memory expansion．

Address Operation：Address inputs must be stable tSA prior to the positive to negative transition of memory enable．It is thus not necessary to hold address informa－ tion stable for more than tHA after the memory is enabled（positive to negative transition of memory enable）．

Note．The timing is different than the DM7489 in that a positive to negative transition of the memory enable must occur for the memory to be selected．

Write Operation：Information present at the data inputs is written into the memory at the selected address by bringing write enable and memory enable low．

Read Operation：The complement of the information which was written into the memory is non－destructively read out at the 4 outputs．This is accomplished by selecting the desired address and bringing memory enable low and write enable high．

When the device is writing or disabled the output assumes a TRI－STATE ${ }^{\circledR}$（Hi－Z）condition．

## Features

－Wide supply voltage range
3.0 V to 5.5 V
－Guaranteed noise margin 1.0 V
－High noise immunity
$0.45 \mathrm{~V}_{\mathrm{CC}}$（typ．）
－Low power TTL
fan out of 2 compatibility
driving 74L
－Input address register
－Low power consumption $250 \mathrm{nW} /$ package（typ．）
＠$V_{C C}=5 \mathrm{~V}$
－Fast access time 140 ns （typ．）at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$
－TRI－STATE output

## Logic and Connection Diagrams



Dual－in－Line Package


Order Number MM54C989J or MM74C989J
See NS Package J16A
Order Number MM74C989N See NS Package N16A

# Absolute Maximum Ratings (Note 1) 

Operating Conditions

|  |  |  | MIN | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Voltage at Any Pin | -0.3 V to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$ | Supply Voltage ( $\mathrm{V}_{\mathrm{CC}}$ ) |  |  |  |
| Package Dissipation | 500 mW | MM54C989 | 4.7 | 5.5 | V |
| Absolute Maximum $\mathrm{V}_{\text {CC }}$ | 7.0 V | MM74C989 | 4.75 | 5.25 | V |
| Lead Temperature (Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ | Temperature ( $\mathrm{T}_{\mathrm{A}}$ ) |  |  |  |
|  |  | MM54C989 | -55 | +125 | ${ }^{\circ} \mathrm{C}$ |
|  |  | MM74C989 | -40 | +85 | ${ }^{\circ} \mathrm{C}$ |
|  |  | Operating $\mathrm{V}_{\text {CC }}$ Range |  | 3. | to 5.5 V |
|  |  | Standby $\mathrm{V}_{\text {CC }}$ Range |  |  | to 5.5 V |

## DC Electrical Characteristics mм54C989/МM74С989

(Min/max limits apply across the temperature and power supply range indicated).

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| VIN(1) | Logical "1" Input Voltage |  | $V_{C C}{ }^{-1.5}$ |  |  | V |
| VIN(O) | Logical " 0 " Input Voltage |  |  |  | 0.8 | v |
| $\operatorname{IIN}(1)$ | Logical "1" Input Current | $V_{\text {IN }}=5 \mathrm{~V}$ |  | 0.005 | 1 | $\mu \mathrm{A}$ |
| IIN(0) | Logical " 0 " Input Current | $V_{\text {IN }}=0$ | -1 | -0.005 |  | $\mu \mathrm{A}$ |
| VOUT(1) | Logical "1" Output Voltage | $\begin{aligned} & \mathrm{I}_{\mathrm{O}}=-360 \mu \mathrm{~A} \\ & \mathrm{I}_{\mathrm{O}}=-150 \mu \mathrm{~A} \end{aligned}$ | $\begin{gathered} 2.4 \\ v_{C C}-0.5 \end{gathered}$ |  |  | V |
| VOUT(0) | Logical "0" Output Voltage | $\mathrm{I}^{\mathrm{O}}=360 \mu \mathrm{~A}$ |  |  | 0.4 | V |
|  | Output Current in High Impedance State | $\mathrm{V}_{\mathrm{O}}=5 \mathrm{~V}$ |  | 0.005 | 1 | $\mu \mathrm{A}$ |
|  |  | $\mathrm{V}_{\mathrm{O}}=0$ | -1 | -0.005 |  | $\mu \mathrm{A}$ |
| ICC | Supply Current (Active) | $\begin{aligned} & \overline{M E}=0 \\ & V_{C C}=5 \mathrm{~V} \end{aligned}$ |  | 0.05 | 150 | $\mu \mathrm{A}$ |
|  | Supply Current (Stand-By) | $\overline{M E}=5 \mathrm{~V}$ |  |  | 3 | $\mu \mathrm{A}$ |

## AC Electrical Characteristics mм54с989/Мм74с989

$T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$

|  | PARAMETER | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ${ }^{\text {taCC }}$ | Access Time From Address |  | 140 | 500 | ns |
| ${ }^{\text {tPD }}$ | Propagation Delay From $\overline{\mathrm{ME}}$ |  | 110 | 360 | ns |
| tSA | Address Input Set-Up Time | 140 | 30 |  | ns |
| tha | Address Input Hold Time | 20 | 15 |  | ns |
| tME | $\overline{\text { Memory Enable Pulse Width }{ }^{\text {a }} \text { ( }{ }^{\text {a }} \text { ( }}$ | 200 | 80 |  | ns |
| ${ }^{\text {m }} \overline{\mathrm{ME}}$ | $\overline{\text { Memory Enable Pulse Width }}$ | 400 | 100 |  | ns |
| ${ }^{\text {t }}$ S | Data Input Set-Up Time | 0 | , |  | ns |
| tHD | Data Input Hold Time | 30 | 20 |  | ns |
| t $\overline{W E}$ | $\overline{\text { Write Enable Pulse Width }}$ | 140 | 70 |  | ns |
| ${ }^{\text {t1 }} \mathrm{H}, \mathrm{tOH}$ | Delay to TRI-STATE ${ }^{\text {® }}, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}$, (Note 4) |  | 100 | 200 | ns |
| CAPACITANCE |  |  |  |  |  |
| CIN | Input Capacity, Any Input, (Note 2) |  | 5 |  | pF |
| COUT | Output Capacity, Any Output, (Note 2) |  | 8 |  | pF |
| CPD | Power Dissipation Capacity, (Note 3) |  | 350 |  | pF |

## AC Electrical Characteristics (Continued)

MM54C989: $T_{A}=-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V} . \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$
MM74C989: $T_{A}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC}}=4.75 \mathrm{~V}$ to $5.25 \mathrm{~V} . \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$

|  | PARAMETER | MM54C989 |  | MM74C989 |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {t }}$ ccc | Access Time From Address |  | 500 |  | 620 | ns |
| tPD1, tPD 0 | Propagation Delay From $\overline{M E}$ |  | 350 |  | 430 | ns |
| tsA | Address Input Set-Up Time | 150 |  | 140 |  | ns |
| tha | Address Input Hold Time | 50 |  | 60 |  | ns |
| ${ }^{\text {tME }}$ | Memory Enable Pulse Width | 250 |  | 310 |  | ns |
| $t \overline{M E}$ | Memory Enable Pulse Width | 520 |  | 400 |  | ns |
| tSD | Data Input Set-Up Time | 0 |  | 0 |  | ns |
| ${ }^{\text {thD }}$ | Data Input Hold Time | 60 |  | 50 |  | ns |
| t $\overline{W E}$ | Write Enable Pulse Width | 220 |  | 180 |  | ns |
| $\mathrm{t}_{1} \mathrm{H}, \mathrm{tOH}$ | Delay to TRI-STATE®, ( Note 4) |  | 200 |  | 200 | ns |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Capacitance is guaranteed by periodic testing.
Note 3: CPD determines the no load AC power consumption for any CMOS device. For complete explanation see 54C/74C Family Characteristics application note, AN-90.
Note 4: See AC test circuit for $\mathrm{t}_{1} \mathrm{H}, \mathrm{t} 0 \mathrm{H}$.

## Truth Table

| $\overline{M E}$ | $\overline{W E}$ | OPERATION | CONDITION OF OUTPUTS |
| :--- | :--- | :--- | :--- |
| L | L | Write | TRI-STATE |
| L | $H$ | Read | Complement of Selected Word |
| $H$ | L | Inhibit, Storage | TRI-STATE |
| $H$ | $H$ | Inhibit, Storage | TRI-STATE |

Read Cycle (Note 1)


Write Cycle (Note 1)


Read-Modify-Write Cycle (Note 1)

${ }^{\mathrm{t}} \mathrm{OH}$


Note 1: $\overline{M E M O R Y ~ E N A B L E ~ m u s t ~ b e ~ b r o u g h t ~ h i g h ~ f o r ~} \mathrm{t}_{\mathrm{ME}} \mathrm{ns}$ between every address change.
Note 2: $t_{r}=t_{f}=20 \mathrm{~ns}$ for all inputs.

## NMC27C16 16,384-Bit $(2048 \times 8)$ UV Erasable CMOS PROM

| Max Access/Current | NMC27C16-1 | NMC27C16-2 | NMC27C16 |
| :--- | :---: | :---: | :---: |
| Access (TAVQV-ns) | 350 | 390 | 450 |
| Active Current (ICC-mA/MHz) | 25 | 25 | 25 |
| Standby Current (ICC- $\mu$ A) | 100 | 100 | 100 |

## General Description

The NMC27C168 is a high speed $16 k$ UV erasable and electrically reprogrammable EPROM ideally suited for applications where fast turn-around, pattern experimentation and low power consumption are important requirements.
The NMC27C16 is packaged in a 24 -pin dual-in-line package with transparent lid. The transparent lid allows the user to expose the chip to ultraviolet light to erase the bit pattern. A new pattern can then be written into the device by following the programming procedure.
This EPROM is fabricated with the reliable, high volume, time proven, CMOS silicon gate technoloǵy.

## Features

- $2048 \times 8$ organization
- Low power during programming
- Access time down to 350 ns
- Single 5 V power supply

Static-no clocks required

- Inputs and outputs TTL compatible during both read and program modes
- TRI-STATE ${ }^{\oplus}$ output

CMOS power consumption

## Block and Connection Diagrams*



Pin Connection During Read or Program

| Mode | Pin Name/Number |  |  |  |  |
| :--- | :---: | :---: | :---: | :---: | :---: |
|  | $\overline{\text { CE/PGM }}$ <br> (E/P) <br> 18 | $\overline{\mathrm{OE}}$ <br> (G) <br> $\mathbf{2 0}$ | VPP <br> $\mathbf{2 1}$ | VCC <br> $\mathbf{2 4}$ | Outputs <br> $9-11,13-17$ |
|  | VIL <br> Program <br> Pulsed VIL <br> to VIH | VIL <br> VIH | 5 | 5 | DOUT |
|  |  |  | 5 | DIN |  |

[^12]Dual-In-Line Package


Pin Names

| $\mathrm{A} 0-\mathrm{A} 10$ | Address Inputs |
| :--- | :--- |
| $\mathrm{O}_{0}-\mathrm{O}_{7}(\mathrm{QO}-\mathrm{Q} 7)$ | Data Outputs |
| $\overline{\mathrm{CE}} / \mathrm{PGM}(\overline{\mathrm{E}} / \mathrm{P})$ | Chip Enable/Program |
| $\overline{\mathrm{OE}}(\mathrm{G})$ | Output Enable |
| VPP | Read 5V, Program 25 V |
| VCC | Power 5 V |
| VSS | Ground |

## Absolute Maximum Ratings (Note 1)

```
Temperature Under Bias
Storage Temperature
VPP Supply Voltage with Respect
    to VSS
Input Voltages with Respect to
    VSS (except VPP) (Note 6)
```

$-25^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
26.5 V to -0.3 V

6 V to -0.3 V

Output Voltages with Respect VCC +0.3 V to -0.3 V to VSS
Power Dissipation 1.5W Lead Temperature (Soldering, 10 seconds) $300^{\circ} \mathrm{C}$

## READ OPERATION (Note 2)

DC Operating Characteristics $T A=0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}, \mathrm{VCC}=5 \mathrm{~V} \pm 5 \%, \mathrm{VPP}=\mathrm{VCC} \pm 0.6 \mathrm{~V}($ Note 3$)$, $\mathrm{VSS}=0 \mathrm{~V}$, unless otherwise noted.

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ILI | Input Current | $\mathrm{VIN}=5.25 \mathrm{~V}$ or VIN $=$ VIL |  |  | 10 | $\mu \mathrm{A}$ |
| ILO | Output Leakage Current | VOUT $=5.25 \mathrm{~V}, \overline{\mathrm{CE}} / \mathrm{PGM}=5 \mathrm{~V}$ |  |  | 10 | $\mu \mathrm{A}$ |
| VIL | Input Low Voltage |  | -0.1 |  | 0.8 | V |
| VIH | Input High Voltage |  | 2.0 |  | VCC + 1 | V |
| VOL1 | Output Low Voltage | $1 \mathrm{OL}=2.1 \mathrm{~mA}$ |  |  | 0.45 | V |
| VOH1 | Output High Voltage | $1 \mathrm{OH}=-400 \mu \mathrm{~A}$ | 2.4 |  |  | V |
| VOL2 | Output Low Voltage | $\mathrm{IOL}=0 \mu \mathrm{~A}$ |  |  | GND + 0.01 | V |
| VOH2 | Output High Voltage | $1 \mathrm{OH}=0 \mu \mathrm{~A}$ | VCC -0.1 |  |  | V |
| IPP1 | VPP Supply Current | $\mathrm{VPP}=5.85 \mathrm{~V}$ |  |  | 10 | $\mu \mathrm{A}$ |
| ICC1 | VCC Supply Current (Active) | $\overline{\mathrm{CE}} / \mathrm{PGM}=\overline{\mathrm{OE}}=\mathrm{VIL}$ (Note 5) |  |  | 25 | $\mathrm{mA} / \mathrm{MHz}$ |
| ICC2 | VCC Supply Current (Standby) | $\overline{\mathrm{CE}} / \mathrm{PGM}=\mathrm{VIH}, \overline{\mathrm{OE}}=\mathrm{VIL}$ |  |  | 100 | $\mu \mathrm{A}$ |

AC Characteristics (Note 2) $\mathrm{TA}=0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}, \mathrm{VCC}=5 \mathrm{~V} \pm 5 \%, \mathrm{VPP}=\mathrm{VCC} \pm 0.6 \mathrm{~V}$ (Note 3), VSS $=0 \mathrm{VV}$, unless otherwise noted.

| Symbol |  | Parameter | Conditions | NMC27C16 |  | NMC27C16-1 |  | NMC27C16-2 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Alternate | Standard |  |  | Min | Max | Min | Max | Min | Max |  |
| $t_{\text {ACC }}$ | TAVQV | Address to Output Delay | $\overline{\mathrm{CE}} / \mathrm{PGM}=\overline{\mathrm{OE}}=\mathrm{VIL}$ |  | 450 |  | 350 |  | 390 | ns |
| $\mathrm{t}_{\text {CE }}$ | TELQV | $\overline{\mathrm{CE}}$ to Output Delay | $\overline{O E}=$ VIL |  | 450 |  | 350 |  | 390 | ns |
| $\mathrm{t}_{\text {OE }}$ | TGLQV | Output Enable to Output Delay | $\overline{\mathrm{CE}} / \mathrm{PGM}=$ VIL |  | 120 |  | 120 | , | 120 | ns |
| $\mathrm{t}_{\mathrm{DF}}$ | TGHQZ | Output Enable High to Output Hi-Z | $\overline{\mathrm{CE}} / \mathrm{PGM}=\mathrm{VIL}$ | 0 | 100 | 0 | 100 | 0 | 100 | ns |
| ${ }^{\text {t }} \mathrm{OH}$ | TAXQX | Address to Output Hold | $\overline{\mathrm{CE}} / \mathrm{PGM}=\overline{\mathrm{OE}}=\mathrm{VIL}$ | 0 |  | 0 |  | 0 |  | ns |
| $\mathrm{t}_{\mathrm{OD}}$ | TEHQZ | $\overline{\mathrm{CE}}$ to Output Hi-Z | $\overline{\mathrm{OE}}=\mathrm{VIL}$ | 0 | 100 | 0 | 100 | 0 | 100 | ns |

Capacitance (Note 4) $\mathrm{TA}=25^{\circ} \mathrm{C}, \mathrm{f}=1 \mathrm{MHz}$

| Symbol | Parameter | Conditions | Typ | Max | Units |
| :---: | :--- | :--- | :---: | :---: | :---: |
| Cl | Input Capacitance | $\mathrm{VIN}=0 \mathrm{~V}$ | 4 | 6 | pF |
| CO | Output Capacitance | VOUT $=0 \mathrm{~V}$ | 8 | 12 | pF |

## AC Test Conditions

Output Load: Input Rise and Fall Times:

1 TTL gate and $\mathrm{CL}=100 \mathrm{pF}$ $\leq 20 \mathrm{~ns}$

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Typical conditions are for operation at: $\mathrm{TA}=25^{\circ} \mathrm{C}, \mathrm{VCC}=5 \mathrm{~V}, \mathrm{VPP}=\mathrm{VCC}$, and $\mathrm{VSS}=0 \mathrm{~V}$.
Note 3: VPP may be connected to VCC except during program. The $\pm 0.6 \mathrm{~V}$ tolerance allows a circuit to switch VPP between the read voltage and the program voltage.
Note 4: Capacitance is guaranteed by periodic testing. $T A=25^{\circ} \mathrm{C}, \mathrm{f}=1 \mathrm{MHz}$.
Note 5: ICC increases for input voltage $\mathrm{V}_{\mathrm{i}}$ : $(\mathrm{VCC}-0.3 \mathrm{~V})>\mathrm{V}_{\mathrm{i}}>+0.3 \mathrm{~V}$ unless in standby mode. During standby, all inputs except $\overline{\mathrm{CE}}$ are disabled and draw no ICC for any $V_{i}$.
Note 6: The inputs (Address, $\overline{O E}, \overline{C E}$ ) may go above VCC by one volt with no latch up danger. Only the output (data inputs during programming) need be restricted to $\mathrm{VCC}+0.3 \mathrm{~V}$ to -0.3 V .


Standby Power-Down Mode ( $\overline{O E}=$ VIL)


[^13]
## PROGRAM OPERATION

## DC Electrical Characteristics and Operating Conditions

(Notes 1 and 2) $\left(\mathrm{TA}=25^{\circ} \mathrm{C} \pm 5^{\circ} \mathrm{C}\right)(\mathrm{VCC}=5 \mathrm{~V} \pm 5 \%, \mathrm{VPP}=25 \mathrm{~V} \pm 1 \mathrm{~V})$

| Symbol | Parameter | Min | Typ | Max | Units |
| :--- | :--- | :--- | :--- | :---: | :---: |
| ILI | Input Leakage Current (Note 3) |  |  | 10 | $\mu \mathrm{~A}$ |
| VIL | Input Low Level | -0.1 |  | 0.8 | V |
| VIH | Input High Level | 2.0 |  | $\mathrm{VCC}+1$ | V |
| ICC | VCC Power Supply Current |  |  | 100 | $\mu \mathrm{~A}$ |
| IPP1 | VPP Supply Current (Note 4) |  |  | 10 | $\mu \mathrm{~A}$ |
| IPP2 | VPP Supply Current During <br> Programming Pulse (Note 5) |  |  | 30 | mA |

## AC Characteristics and Operating Conditions

(Notes 1,2 , and 6) $\left(\mathrm{TA}=25^{\circ} \mathrm{C} \pm 5^{\circ} \mathrm{C}\right)(\mathrm{VCC}=5 \mathrm{~V} \pm 5 \%, \mathrm{VPP}=25 \mathrm{~V} \pm 1 \mathrm{~V})$

| Symbol |  | Parameter | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Alternate | Standard |  |  |  |  |  |
| $t_{\text {AS }}$ | TAVPH | Address Set-up Time | 2 |  |  | $\mu \mathrm{S}$ |
| $\mathrm{t}_{\text {OS }}$ | TGHPH | $\overline{\text { OE Set-up Time }}$ | 2 |  |  | $\mu \mathrm{S}$ |
| $\mathrm{t}_{\mathrm{DS}}$ | TDVPH | Data Set-up Time | 2 |  |  | $\mu \mathrm{S}$ |
| $t_{\text {AH }}$ | TPLAX | Address Hold Time | 2 |  |  | $\mu \mathrm{S}$ |
| $\mathrm{t}_{\mathrm{OH}}$ | TPLGX | $\overline{\text { OE Hold Time }}$ | 2 |  |  | $\mu \mathrm{S}$ |
| $\mathrm{t}_{\mathrm{DH}}$ | TPLDX | Data Hold Time | 2 |  |  | $\mu \mathrm{S}$ |
| $\mathrm{t}_{\mathrm{DF}}$ | TGHQZ | Output Disable to Output TRI-STATE Delay (Note 4) | 0 |  | 100 | ns |
| $\mathrm{t}_{\text {OE }}$ | TGLQV | Output Enable to Output Delay (Note 4) |  |  | 120 | ns |
| $t_{\text {PW }}$ | TPHPL | Program Pulse Width | 45 | 50 | 55 | ms |
| $t_{\text {PR }}$ | TPH1PH2 | Program Pulse Rise Time | 5 |  |  | ns |
| $t_{\text {PF }}$ | TPL2PL1 | Program Pulse Fall Time | 5 |  |  | ns |

Note 1: VCC must be applied at the same time or before VPP and removed after or at the same time as VPP. To prevent damage to the device it must not be inserted into a board with power applied.
Note 2: Care must be taken to prevent overshoot of the VPP supply when switching to +25 V .
Note 3: $0.45 \mathrm{~V} \leq \mathrm{VIN} \leq 5.25 \mathrm{~V}$
Note 4: $\overline{C E} / P G M=$ VIL, VPP $=V C C$
Note 5: VPP $=26 \mathrm{~V}$
Note 6: Transition times $\leq 20$ ns unless noted otherwise.

## Timing Diagram*



## Functional Description

## device operation

The NMC27C16 has 3 modes of operation in the normal system environment. These are shown in Table I.

## Read Mode

The NMC27C16 read operation requires that $\overline{O E}=V I L$, $\overline{\mathrm{CE}} / \mathrm{PGM}=\mathrm{VIL}$ and that addresses A0-A10 have been stabilized. Valid data will appear on the output pins after $t_{A C C}$, $t_{\text {OE }}$ or $t_{\text {CE }}$ times (see Switching Time Waveforms) depending on which is limiting.

## Deselect Mode

The NMC27C16 is deselected by making $\overline{\mathrm{OE}}=\mathrm{VIH}$. This mode is independent of CE/PGM and the condition of the addresses. The outputs are $\mathrm{Hi}-\mathrm{Z}$ when $\overline{\mathrm{OE}}=\mathrm{VIH}$. This allows OR-tying 2 or more NMC27C16s for memory expansion.

## Standby Mode (Power Down)

The NMC27C16 may be powered down to the standby mode by making $\overline{\mathrm{CE}} / \mathrm{PGM}=\mathrm{VIH}$. This is independent of $\overline{\mathrm{OE}}$ and automatically puts the outputs in their $\mathrm{Hi}-\mathrm{Z}$ state. The power is reduced to $0.4 \%(500 \mu \mathrm{~W}$ max) of the normal operating power. VCC must be maintained at 5V. Access time at power up remains either $\mathrm{t}_{\mathrm{ACC}}$ or $\mathrm{t}_{\mathrm{CE}}$ (see Switching Time Waveforms).

TABLE I. OPERATING MODES $(\mathrm{VCC}=5 \mathrm{~V})$

| Mode | Pin Name/Number |  |  |
| :--- | :---: | :---: | :---: |
|  | $\overline{\text { CE/PGM }}$ <br> (E/P) <br> 18 | $\overline{\text { OE }}$ <br> (G) <br> 20 | Outputs <br> $9-11,13-17$ |
|  | VIL | VIL | DOUT |
| Deselect | Don't Care | VIH | Hi-Z |
| Standby | VIH | Don't Care | Hi-Z |

## PROGRAMMING

The NMC27C16 is shipped from National completely erased. All bits will be at a "1" level (output high) in this initial state and after any full erasure. Table II shows the 3 programming modes.

## Program Mode

The NMC27C16 is programmed by introducing " 0 "s into the desired locations. This is done 8 bits (a byte) at a time. Any individual address, a sequence of addresses, or addresses chosen at random may be programmed. Any or all of the 8 bits associated with an address location may be programmed with a single program pulse applied to the chip enable pin. All input voltage levels, including the program pulse on chip enable are TTL compatible. The programming sequence is:

With VPP $=25 \mathrm{~V}, \mathrm{VCC}=5 \mathrm{~V}, \overline{\mathrm{OE}}=\mathrm{VIH}$ and $\overline{\mathrm{CE}} / \mathrm{PGM}=\mathrm{VIL}$, an address is selected and the desired data word is applied to the output pins. (VIL = " 0 " and VIL = " 1 " for both address and data.) After the address and data signals are stable the program pin is pulsed from VIL to VIH with a pulse width between 45 ms and 55 ms .

Multiple pulses are not needed but will not cause device damage. No pins should be left open. A high level (VIH or higher) must not be maintained longer than $\mathrm{t}_{\mathrm{PW}(\mathrm{MAX})}$ on the program pin during programming. NMC27C16s may be programmed in parallel with the same data in this mode.

TABLE II. PROGRAMMING MODES $(\mathrm{VCC}=5 \mathrm{~V})$

| Mode | Pin Name/Number |  |  |  |
| :--- | :---: | :---: | :---: | :---: |
|  | $\overline{\text { CE/PGM }}$ |  |  |  |
|  | (E/P) <br> 18 | $\overline{\text { OE }}$ <br> (G) <br> 20 | VPP <br> $\mathbf{2 1}$ | Outputs Q <br> $9-11,13-17$ |
| Program | Pulsed VIL <br> to VIH <br> VIH | 25 | DIN |  |
| Program Verify | VIL | VIL | $25(5)$ | DOUT |
| Program Inhibit | VIL | VIH | 25 | Hi-Z |

[^14]
## Functional Description (Continued)

## Program Verify Mode

The programming of the NMC27C16 may be verified either 1 word at a time during the programming (as shown in the Timing Diagram) or by reading all of the words out at the end of the programming sequence. This can be done with $\mathrm{VPP}=25 \mathrm{~V}$ (or 5 V ) in either case.

## Program Inhibit Mode

The program inhibit mode allows programming several NMC27C16s simultaneously with different data for each one by controlling which ones receive the program pulse. All similar inputs of the NMC27C16 may be paralleled. Pulsing the program pin (from VIL to VIH) will program a unit while inhibiting the program pulse to a unit will keep it from being programmed and keeping $\overline{O E}=$ VIH will put its outputs in the $\mathrm{Hi}-\mathrm{Z}$ state.

## ERASING

The NMC27C16 is erased by exposure to high intensity ultraviolet light through the transparent window. This exposure discharges the floating gate to its initial state through induced photo current. It is recommended that the NMC27C16 be kept out of direct sunlight. The UV content of sunlight may cause a partial erasure of some bits in
a relatively short period of time. Direct sunlight can also cause temporary functional failure. Extended exposure to room level fluorescent lighting will also cause erasure. An opaque coating (paint, tape, label, etc.) should be placed over the package window if this product is to be operated under these lighting conditions. Covering the window also reduces ICC due to photodiode currents.

An ultraviolet source of $2537 \AA$ yielding a total integrated dosage of 15 watt-seconds $/ \mathrm{cm}^{2}$ is required. This will erase the part in approximately 15 to 20 minutes if a UV lamp with a $12,000 \mu \mathrm{~W} / \mathrm{cm}^{2}$ power rating is used. The NMC27C16 to be erased should be placed 1 inch away from the lamp and no filters should be used.

An erasure system should be calibrated periodicaily. The distance from lamp to unit should be maintained at 1inch. The erasure time is increased by the square of the distance (if the distance is doubled the erasure time goes up by a factor of 4). Lamps lose intensity as they age. When a lamp is changed, the distance is changed, or the lamp is aged, the system should be checked to make certain full erasure is occurring. Incomplete erasure will cause symptoms that can be misleading. Programmers, components, and system designs have been erroneously suspected when incomplete erasure was the basic problem.

## NMC6504 4096-Bit (4096 $\times 1$ ) Static RAM

## General Description

The NMC6504 is a static CMOS random access read/write memory organized as 4096 words of 1 bit each. This device is fabricated with National Semiconductor's silicon-gate CMOS technology and is fully compatible to the TTL environment. Synchronous operation is provided by on-chip address, data, and write latches. The ENABLE input serves as the device strobe controlling the latching functions. The TRI-STATE ${ }^{\oplus}$ output, in conjunction with the ENABLE input, allows easy memory expansion.

## Features

- Industry standard pinout
- Low data retention voltage -2 V
- Low speed/power product
- TTL compatible - all inputs and outputs
- TRI-STATE ${ }^{\oplus}$ outputs for bus operation
- High output drive
- High noise immunity
- Military temperature range available
- On-chip address registers (latches)
- Common I/O - high density packaging
- Output data latches
- Input data latches
- Select latch for microprocessor interface


## Connection Diagram



Logic Symbol


## Pin Names

| A0-A11 | Address Inputs |
| :--- | :--- |
| $\overline{\mathrm{E}}$ | Chip Enable |
| $\bar{W}$ | Write Enable |
| D | Data Input |
| Q | Data Output |

## Functional Description

An NMC6504 memory cycle is initiated by the falling edge of the ENABLE ( $\overline{\mathrm{E}}$ ) input which latches the address information into the on-chip registers. On-chip latches allow selection of a read, early write, or read-modify-write cycle as a function of the ENABLE and WRITE $(\bar{W})$ input levels and timing. Data output is enabled by the falling edge of the ENABLE input and disabled by the rising edge except when performing an early write cycle. The input and output data latches are transparent except during the write pulse (not the WRITE input).

When performing a read cycle a minimum ENABLE LOW time is required to assure valid data at the output. This minimum LOW time is defined as the enable access time. A minimum ENABLE HIGH time is required to return the columns to the HIGH state and to precharge the sense amplifiers in preparation of the next cycle.

An early write cycle is performed by preceding the ENABLE with the HIGH to LOW transition of the WRITE input. The WRITE input level is latched, and set-up and hold times must be met. The data output is not enabled during an early write cycle. The input data set-up and hold times are referenced to the leading edge of the write pulse, which is initiated by the falling edge of the ENABLE input and terminated by the rising edge of the ENABLE.

A read-modify-write cycle is performed as a read cycle, for the enable access time, followed by the write pulse which is initiated by the falling edge of the WRITE input and terminated by the rising edge of either the ENABLE or WRITE input, whichever occurs first. The input data set-up and hold times are referenced to the falling edge of the WRITE input. Data is latched when the WRITE input goes LOW, allowing the modified data to be written into the memory while continuing to read the original data.

## Block Diagram



Absolute Maximum Ratings

| Supply Voltage VCC | 7 V |
| :--- | ---: |
| Voltage at Any Pin | -0.3 V to $\mathrm{VCC}+0.3 \mathrm{~V}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Package Dissipation | 500 mW |
| Lead Temperature (Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ |

## Operating Range

|  | Min | Max |
| :---: | :---: | ---: |
| Supply Voltage |  |  |
| NMC6504-9 | 4.5 V | 5.5 V |
| NMC6504-2 | 4.5 V | 5.5 V |
| NMC6504-5 | 4.75 V | 5.25 V |
| Temperature |  |  |
| NMC6504.9 | $-40^{\circ} \mathrm{C}$ | $85^{\circ} \mathrm{C}$ |
| NMC6504-2 | $-55^{\circ} \mathrm{C}$ | $125^{\circ} \mathrm{C}$ |
| NMC6504-5 | $0^{\circ} \mathrm{C}$ | $75^{\circ} \mathrm{C}$ |

DC Electrical Characteristics over the operating range, unless otherwise noted

| Symbol | Parameter | Conditions | NMC6504-9, NMC6504-2 |  | NMC6504.5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Max | Min | Max |  |
| VCCDR | Data Retention Supply Voltage | $V I=V C C, G N D$ | 2.0 |  | 2.0 |  | V |
| ICCSB | Standby Supply Current |  |  | 50 |  | 500 | $\mu \mathrm{A}$ |
| ICCOP* | Operating Supply Current | $\begin{aligned} & \mathrm{f}=1 \mathrm{MHz}, 1 \mathrm{O}=0 \\ & \mathrm{VI}=\mathrm{VCC} \text { or } \mathrm{GND} \end{aligned}$ |  | 10 |  | 10 | mA |
| ICCDR | Data Retention Supply Current | $\begin{aligned} & V C C=3.0 V, I O=0, \\ & V I=V C C \text { or } G N D \end{aligned}$ |  | 25 |  | 500 | $\mu \mathrm{A}$ |
| 11 | Input Leakage Current | $V I=V C C, G N D$ | -1.0 | +1.0 | -10 | + 10 | $\mu \mathrm{A}$ |
| VIL | Input Low Voltage |  | -0.3 | 0.8 | -0.3 | 0.8 | V |
| VIH | Input High Voltage |  | VCC - 2.0 | $V C C+0.3$ | VCC -2 | $\mathrm{VCC}+0.3$ | V |
| IOZ | Output Leakage Current | $\mathrm{VI}=\mathrm{VCC}, \mathrm{GND}$ | -1.0 | +1.0 | -10 | +10 | $\mu \mathrm{A}$ |
| VOL | Output Low Voltage | $1 \mathrm{OL}=2.0 \mathrm{~mA}$ |  | 0.4 |  | 0.45 | V |
| VOH | Output High Voltage | $1 \mathrm{OH}=-1.0 \mathrm{~mA}$ | 2.4 |  | 2.4 |  | V |
| Cl | Input Capacitance | $\mathrm{f}=1 \mathrm{MHz}$ |  | 8 |  | 8 | pF |
| CO | Output Capacitance | $\mathrm{f}=1 \mathrm{MHz}$ |  | 10 |  | 10 | pF . |

*ICCOP is proportional to operating frequency.

## AC Test Conditions

Input Rise and Fall Times: $\leq 20 \mathrm{~ns}$
All Timing Reference Levels: $1 / 2 \mathrm{VCC}$
Output Load: 1 TTL Load, 50 pF

## NMC6504 Bit Map and Address Decoding




## Read Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6504-9, NMC6504-2 |  | NMC6504.5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 20 |  | 20 |  | ns |
| TELAX | Address Hold Time | 50 |  | 50 |  | ns |
| TELQV | Enable Access Time |  | 300 |  | 350 | ns |
| TAVQV | Address Access Time |  | 320 |  | 370 | ns |
| TELEH | Enable (E) Minimum Low Time | 300 |  | 350 |  | ns |
| TELEL | Read or Write Cycle Time | 420 |  | 500 |  | ns |
| TEHEL | Enable (E) Minimum High Time | 120 |  | 150 |  | ns |
| TELQX | Output Enable from Enable ( $\overline{\mathrm{E}})$ |  | 100 |  | 100 | ns |
| TEHQZ | Output Disable from Enable (E) |  | 100 |  | 100 | ns |

## Read Cycle Waveforms



Write Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6504-9, NMC6504-2 |  | NMC6504-5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 20 |  | 20 |  | ns |
| TELAX | Address Hold Time | 50 |  | 50 |  | ns |
| TWLWH | Write Pulse Width ( $\bar{W}$ Low) | 80 |  | 100 |  | ns |
| TELEL | Read or Write Cycle Time | 420 |  | 500 |  | ns |
| TELEH | Enable (E) Minimum Low Time | 300 |  | 350 |  | ns |
| TDVWL | Data Set-up Time | 0 |  | 30 |  | ns |
| TEHEL | Enable (E) Minimum High Time | 120 |  | 150 |  | ns |
| TWLDX | Data Hold Time | 80 |  | 100 |  | ns |
| TELWH | Write Pulse Width (E and $\bar{W}$ Low) | 80 |  | 100 |  | ns |
| TELWL | Early Write Output Hi-Z Time | 0 |  | 0 |  | ns |
| TWLEH | Write Pulse Width ( $\bar{W}$ and $\bar{E}$ Low) | 200 |  | 250 |  | ns |
| TELQX | Output Enable from $\overline{\mathrm{E}}$ |  | 100 |  | 100 | ns |
| TELQV | Enable Access Time |  | 300 |  | 350 | ns |
| TEHQZ | Output Disable from $\bar{E}$ |  | 100 |  | 100 | ns |

## Write Cycle Waveforms



Early Write Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6504-9, NMC6504-2 |  | NMC6504.5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 20 |  | 20 |  | ns |
| TELAX | Address Hold Time | 50 |  | 50 |  | ns |
| TELWH | Write Pulse Width (E $\bar{E}$ and $\bar{W}$ Low) | 80 |  | 100 |  | ns |
| TDVEL | Early Write Data Set-up Time | 0 |  | 30 |  | ns |
| TELEH | Enable (E) Minimum Low Time | 300 |  | 350 |  | ns |
| TWLEL | Early Write Set-up Time | 0 |  | 0 |  | ns |
| TEHEL | Enable ( $\overline{\mathrm{E}}$ ) Minimum High Time | 120 |  | 150 |  | ns |
| TELDX | Early Write Data Hold Time | 80 |  | 100 |  | ns |
| TELEL | Read or Write Cycle Time | 420 |  | 500 |  | ns |

## Early Write Cycle Waveforms



Read-Modify-Write Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6504-9, NMC6504-2 |  | NMC6504-5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 20 |  | 20 |  | ns |
| TELAX | Address Hold Time | 50 |  | 50 |  | ns |
| TELQV | Enable Access Time |  | 300 |  | 350 | ns |
| TAVQV | Address Access Time |  | 320 |  | 370 | ns |
| TEHEL | Enable ( $\overline{\mathrm{E}}$ ) Minimum High Time | 120 |  | 150 |  | ns |
| TWHEL | $\bar{W}$ Read Mode Set-up Time | 0 |  | 0 |  | ns |
| TWLEH | Write Pulse Width ( $\bar{W}$ and $\bar{E}$ Low) | 200 |  | 250 |  | ns |
| TQVWL | Data Valid to Write Time | 0 |  | 0 |  | ns |
| TWLWH | Write Pulse Width ( $\bar{W}$ Low) | 80 |  | 100 |  | ns |
| TWLDX | Data Hold Time | 80 |  | 100 |  | ns |
| TELQX | Output Enable from Enable ( $\overline{\mathrm{E}})$ |  | 100 |  | 100 | ns |
| TEHQZ | Output Disable from Enable (E) |  | 100 |  | 100 | ns |
| TDVWL | Data Set-up Time | 0 |  | 30 |  | ns |

## Read-Modify-Write Cycle Waveforms



NMC6508 1024-Bit ( $1024 \times 1$ ) Static RAM

## General Description

The NMC6508 is a static CMOS random access read/write memory organized as 1024 words of 1 bit each. This device is fabricated with National Semiconductor's silicon-gate CMOS technology and is fully compatible to the TTL environment. Synchronous operation is provided by the onchip latches for the address inputs. The NMC6508 may be used in common I/O applications by externally connecting the data input and output terminals. The TRI-STATE ${ }^{\circledR}$ output, in conjunction with the ENABLE input, allows for easy memory expansion.

## Connection Diagram

Dual-In-Line Package


TOP VIEW
Order Number NMC6508J-2, NMC6508J-9 or NMC6508J-5
See NS Package J18A
Order Number NMC6508N-5
See NS Package N18A

Pin Names

| A0-A9 | Address Inputs |
| :--- | :--- |
| $\overline{\mathrm{E}}$ | Chip Enable |
| $\bar{W}$ | Write Enable |
| D | Data Input |
| Q | Data Output |



## Functional Description

An NMC6508 memory cycle is initiated by the falling edge of the ENABLE ( $\overline{\mathrm{E}}$ ) input, which latches the address information into the on-chip registers. The output buffer is enabled when the WRITE ( $\bar{W}$ ) input is HIGH and the ENABLE input is LOW.

When performing a read cycle a minimum ENABLE LOW time is required to assure valid data at the output. This minimum LOW time is defined as the device enable access time. A minimum ENABLE HIGH time is required to
return the columns to the HIGH state and to precharge the sense amplifiers in preparation of the next memory cycle.

When performing a write cycle, the minimum ENABLE LOW time is required to enter new data. The write pulse is created by the coincident LOW of the ENABLE and WRITE inputs. The data set-up and hold times are referenced to the rising edge of either the ENABLE or WRITE input, whichever occurs first.

## Block Diagram



Absolute Maximum Ratings
Supply Voltage VCC
Voltage at Any Pin
Storage Temperature Range
Package Dissípation
Lead Temperature(Soldering, 10 seconds)
7 V
-0.3 V to $\mathrm{VCC}+0.3 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$300^{\circ} \mathrm{C}$

Operating Range

|  | Min | Max |
| :--- | ---: | ---: |
| Supply Voltage |  |  |
| NMC6508B-9 | 4.5 V | 5.5 V |
| NMC6508B-2 | 4.5 V | 5.5 V |
| NMC6508-9 | 4.5 V | 5.5 V |
| NMC6508-2 | 4.5 V | 5.5 V |
| NMC6508-5 | 4.75 V | 5.25 V |
| Temperature |  |  |
| NMC6508B-9 | $-40^{\circ} \mathrm{C}$ | $85^{\circ} \mathrm{C}$ |
| NMC6508B-2 | $-55^{\circ} \mathrm{C}$ | $125^{\circ} \mathrm{C}$ |
| NMC6508-9 | $-40^{\circ} \mathrm{C}$ | $85^{\circ} \mathrm{C}$ |
| NMC6508-2 | $-55^{\circ} \mathrm{C}$ | $125^{\circ} \mathrm{C}$ |
| NMC6508-5 | $0^{\circ} \mathrm{C}$ | $75^{\circ} \mathrm{C}$ |

DC Electrical Characteristics over the operating range, unless otherwise noted

| Symbol | Parameter | Conditions | NMC6508B-9, NMC6508B-2 <br> NMC6508-9, NMC6508-2 |  | NMC6508-5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Max | Min | Max |  |
| VCCDR | Data Retention Supply Voltage | $\mathrm{VI}=\mathrm{VCC}, \mathrm{GND}$ | 2.0 |  | 2.0 |  | V |
| ICCSB | Standby Supply Current |  |  | 10 |  | 100 | $\mu \mathrm{A}$ |
| ICCOP* | Operating Supply Current | $\begin{aligned} & f=1 \mathrm{MHz}, I O=0, \\ & V I=V C C \text { or } G N D \end{aligned}$ |  | 4 |  | 4 | mA |
| ICCDR | Data Retention Supply Current | $\begin{aligned} & V C C=3.0 V, I O=0, \\ & V I=V C C \text { or } G N D \end{aligned}$ |  | 10 |  | 100 | $\mu \mathrm{A}$ |
| II | Input Leakage Current | $\mathrm{VI}=\mathrm{VCC}, \mathrm{GND}$ | -1.0 | +1.0 | -1.0 | +1.0 | $\mu \mathrm{A}$ |
| VIL | Input Low Voltage |  | -0.3 | 0.8 | -0.3 | 0.8 | V |
| VIH | Input High Voltage |  | VCC -2.0 | VCC +0.3 | VCC-2 | VCC +0.3 | V |
| IOZ | Output Leakage Current | $\mathrm{VI}=\mathrm{VCC}, \mathrm{GND}$ | -1.0 | +1.0 | -1.0 | +1.0 | $\mu \mathrm{A}$ |
| VOL | Output Low Voltage | $\mathrm{IOL}=3.2 \mathrm{~mA}$ |  | 0.4 |  | 0.4 | V |
| VOH | Output High Voltage | $1 \mathrm{OH}=-0.4 \mathrm{~mA}$ | 2.4 |  | 2.4 |  | V |
| Cl | Input Capacitance | $\mathrm{f}=1 \mathrm{MHz}$ |  | 6 |  | 6 | pF |
| CO | Output Capacitance | $\mathrm{f}=1 \mathrm{MHz}$ |  | 10 |  | 10 | pF |

*ICCOP is proportional to operating frequency.

## AC Test Conditions

Input Rise and Fall Times: $\leq 20 \mathrm{~ns}$
All Timing Reference Levels: $1 / 2$ VCC
Output Load: 1 TTL Load, 50 pF
NMC6508 Bit Map and Address Decoding


Read Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6508B-9 NMC6508B-2 |  | NMC6508-9 <br> NMC6508-2 |  | NMC6508-5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 0 |  | 0 |  | 10 |  | ns |
| TELAX | Address Hold Time | 40 |  | 50 | . | 70 |  | ns |
| TELQV | Enable Access Time |  | 180 |  | 250 |  | 300 | ns |
| TAVQV | Address Access Time |  | 180 |  | 250 |  | 310 | ns |
| TELEH | Enable (E) Minimum Low Time | 180 |  | 250 |  | 300 |  | ns |
| TELQX | Output Enable from Enable ( $\overline{\mathrm{E}}$ ) |  | 120 |  | 160 |  | 200 | ns |
| TEHQZ | Output Disable from Enable (E) |  | 120 |  | 160 |  | 200 | ns |
| TEHEL | Enable (E) Minimum High Time | 100 |  | 100 |  | 150 |  | ns |
| TELEL | Read or Write Cycle Time | 280 |  | 350 |  | 450 |  | ns |

## Read Cycle Waveforms



Write Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6508B-9 NMC6508B-2 |  | NMC6508.9 <br> NMC6508-2 |  | NMC6508-5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 0 |  | 0 |  | 10 |  | ns |
| TELAX | Address Hold Time | 40 |  | 50 |  | 70 |  | ns |
| TEHEL | Enable ( $\overline{\mathrm{E}}$ ) Minimum High Time | 100 |  | 100 |  | 150 |  | ns |
| TDVWH | Data Set-up Time | 80 |  | 110 |  | 130 |  | ns |
| TELWH | Write Pulse Width ( $\bar{E}$ and $\bar{W}$ Low) | 100 |  | 130 |  | 160 | , | ns |
| TWLWH | Write Pulse Width ( $\bar{W}$ Low) | 100 |  | . 130 |  | 160 |  | ns |
| TELEL | Read or Write Cycle Time | 280 |  | 350 |  | 450 |  | ns |
| TWHDM | Data Hold Time | 0 |  | 0 |  | 0 |  | ns |
| TWLEH | Write Pulse Width ( $\overline{\mathrm{E}}$ and $\bar{W}$ Low) | 100 |  | 130 |  | 160 |  | ns |
| TELEH | Enable (E) Minimum Low Time | 180 |  | 250 |  | 300 | - | ns |
| TELQX | Output Enable from $\overline{\mathrm{E}}$ |  | 120 |  | 160 |  | 200 | ns |
| TWLQZ | Output Disable from $\bar{W}$ |  | 120 |  | 160 |  | 200 | ns |
| TWHQX | Output Enable from $\bar{W}$ |  | 120 |  | 160 |  | 200 | ns |
| TEHQZ | Output Disable from $\bar{E}$ |  | 120 |  | 160 |  | 200 | ns |

## Write Cycle Waveforms



Read-Modify-Write Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6508B-9 NMC6508B-2 |  | NMC6508-9 <br> NMC6508-2 |  | NMC6508-5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 0 |  | 0 |  | 10 |  | ns |
| TELAX | Address Hold Time | 40 |  | 50 |  | 70 |  | ns |
| TELQV | Enable Access Time |  | 180 |  | 250 |  | 300 | ns |
| TAVQV | Address Access Time |  | 180 |  | 250 |  | 310 | ns |
| TEHEL | Enable (E) Minimum High Time | 100 |  | 100 |  | 150 |  | ns |
| TWHDM | Data Hold Time | 0 |  | 0 |  | 0 |  | ns |
| TQVWL | Data Valid to Write Time | 0 |  | 0 |  | 0 |  | ns |
| TWHEL | $\bar{W}$ Read Mode Set-up Time | 0 |  | 0 |  | 0 |  | ns |
| TWLWH | Write Pulse Width ( $\bar{W}$ Low) | 100 |  | 130 |  | 160 |  | ns |
| TELQX | Output Enable from Enable (E) |  | 120 |  | 160 |  | 200 | ns |
| TEHQZ | Output Disable from Enable ( $\overline{\mathbf{E}}$ ) |  | 120 |  | 160 |  | 200 | ns |
| TWLQZ | Output Disable from Write ( $\bar{W}$ ) |  | 120 |  | 160 |  | 200 | ns |
| TDVWH | Data Set-up Time | 80 |  | 110 |  | 130 |  | ns |
| TWHQX | Output Enable from Write ( $\bar{W}$ ) |  | 120 |  | 160 |  | 200 | ns |

Read-Modify-Write Cycle Waveforms


* Output enable can be avoided by preceding the rising edge of $\bar{W}$ with the rising edge of $\bar{E}$ by time; TEHQZ


## NMC6514 4096-Bit (1024 $\times 4$ ) Static RAM

## General Description

The NMC6514 is a static CMOS random access read/write memory organized as 1024 words of 4 bits each. This device is fabricated with National Semiconductor's silicon-gate CMOS technology and is fully compatible with the TTL environment. Synchronous operation is provided by on-chip address latches. The ENABLE input serves as the device strobe controlling the address latching function. The data I/O terminals, when not output data enabled, represent a high impedance for easy memory expansion.

## Features

- Industry standard pinout
- Low data retention voltage - 2 V
- Low speed/power product
- TTL compatible - all inputs and outputs
- TRI-STATE ${ }^{\oplus}$ outputs for bus operation
- High output drive
- High noise immunity
- Military temperature range available
- On-chip address registers (latches)
- Common I/O - high density packaging

Connection Diagram

Dual-In-Line Package


Order Number NMC6514J.2, NMC6514J. 9
or NMC6514J-5
See NS Package J18A

Order Number NMC6514N-5 See NS Package N18A

Pin Names

| A0-A9 | Address Inputs |
| :--- | :--- |
| $\overline{\bar{E}}$ | Chip Enable |
| $\bar{W}$ | Write Enable |
| DQ0-DQ3 | Data In/Out |



## Functional Description

An NMC6514 memory cycle is initiated by the falling edge of the ENABLE ( $\overline{\mathrm{E}}$ ) input, which latches the address information into the on-chip registers. Read, write, the read-modify-write cycles are selected as a function of the ENABLE and WRITE $(\bar{W})$ input levels and timing. Data output is enabled by the falling edge of the ENABLE input and disabled by the rising edge when the WRITE input is HIGH. The output is disabled when writing.
When performing a read cycle a minimum ENABLE LOW time is required to assure valid data at the output. This minimum LOW time is defined as the device enable access time. A minimum ENABLE HIGH time is required to return the columns to the HIGH state and to precharge the sense amplifiers in preparation of the next cycle.

When performing a write cycle a minimum ENABLE LOW time is required to enter the new data. The write pulse is created by the coincident LOW of the ENABLE and WRITE inputs. The data set-up and hold time are referenced to the rising edge of either the ENABLE or WRITE inputs whichever occurs first.

A read-modify-write cycle is performed as a read cycle, for the enable access time, followed by the write pulse caused by the LOW time of the WRITE input. The output data is disabled by the falling edge of the WRITE input, and input data, meeting the set-up and hold requirements must be provided.

## Block Diagram



## Absolute Maximum Ratings

|  |  |
| :--- | ---: |
| Supply Voltage VCC | 7 V |
| Voltage at Any Pin | -0.3 V to $\mathrm{VCC}+0.3 \mathrm{~V}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Package Dissipation | 500 mW |
| Lead Temperature (Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ |

Operating Range

|  | Min | Max |
| :---: | :---: | ---: |
| Supply Voltage |  |  |
| NMC6514-9 | 4.5 V | 5.5 V |
| NMC6514-2 | 4.5 V | 5.5 V |
| NMC6514-5 | 4.75 V | 5.25 V |
| Temperature |  |  |
| NMC6514-9 | $-40^{\circ} \mathrm{C}$ | $85^{\circ} \mathrm{C}$ |
| NMC6514-2 | $-55^{\circ} \mathrm{C}$ | $125^{\circ} \mathrm{C}$ |
| NMC6514-5 | $0^{\circ} \mathrm{C}$ | $75^{\circ} \mathrm{C}$ |

DC Electrical Characteristics over the operating range, unless otherwise noted

| Symbol | Parameter | Conditions | NMC6514-9, NMC6514-2 |  | NMC6514.5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Max | Min | Max |  |
| VCCDR | Data Retention Supply Voltage | $\mathrm{VI}=\mathrm{VCC}, \mathrm{GND}$ | 2.0 |  | 2.0 |  | V |
| ICCSB | Standby Supply Current |  |  | 50 |  | 500 | ${ }_{\mu} \mathrm{A}$ |
| ICCOP* | Operating Supply Current | $\begin{aligned} & f=1 \mathrm{MHz}, \mathrm{IO}=0, \\ & \mathrm{VI}=\mathrm{VCC} \text { or } \mathrm{GND} \end{aligned}$ |  | 10 |  | 10 | mA |
| - ICCDR | Data Retention Supply Current | $\begin{aligned} & V C C=3.0 V, 1 O=0, \\ & V I=V C C \text { or } G N D \end{aligned}$ |  | 25 |  | 500 | $\mu \mathrm{A}$ |
| 11 | Input Leakage Current | $\mathrm{VI}=\mathrm{VCC}, \mathrm{GND}$ | -1.0 | +1.0 | -10 | +10 | $\mu \mathrm{A}$ |
| VIL | Input Low Voltage |  | -0.3 | 0.8 | -0.3 | 0.8 | V |
| VIH | Input High Voltage |  | VCC -2.0 | VCC +0.3 | VCC-2 | $V C C+0.3$ | V |
| IOZ | Output Leakage Current | $\mathrm{VI}=\mathrm{VCC}, \mathrm{GND}$ | -1.0 | +1.0 | -10 | +10 | $\mu \mathrm{A}$ |
| VOL | Output Low Voltage | $1 \mathrm{OL}=2.0 \mathrm{~mA}$ |  | 0.4 |  | . 0.4 | V |
| VOH | Output High Voltage | $1 \mathrm{OH}=-1.0 \mathrm{~mA}$ | 2.4 |  | 2.4 |  | V |
| Cl | Input Capacitance | $f=1 \mathrm{MHz}$ |  | 8 |  | 8 | pF |
| CO | Output Capacitance | $\mathrm{f}=1 \mathrm{MHz}$ |  | 10 |  | 10 | pF |

*ICCOP is proportional to operating frequency.

## AC Test Conditions

Input Rise and Fall Times: $\leq 20 \mathrm{~ns}$
All Timing Reference Levels: $1 / 2 \mathrm{VCC}$
Output Load: 1 TTL Load, 50 pF

## NMC6514 Bit Map and Address Decoding



Read Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6514.9, NMC6514-2 |  | NMC6514.5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 20 |  | 20 |  | ns |
| TELAX | Address Hold Time | 50 |  | 50 |  | ns |
| TELQV | Enable Access Time |  | 300 |  | 350 | ns |
| TAVQV | Address Access Time |  | 320 |  | 370 | ns |
| TELEH | Enable ( $\overline{\mathrm{E}}$ ) Minimum Low Time | 300 |  | 350 |  | ns |
| TEHEL | Enable (E) Minimurn High Time | 120 |  | 150 |  | ns |
| TELQX | Output Enable from Enable ( $\overline{\mathrm{E}}$ ) |  | 100 |  | 100 | ns |
| TEHQZ | Output Disable from ( $\overline{\mathrm{E}}$ ) |  | 100 |  | 100 | ns |
| TELEL | Read or Write Cycle Time | 420 |  | 500 |  | ns |

## Read Cycle Waveforms



Write Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6514.9, NMC6514-2 |  | NMC6514.5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 20 |  | 20 |  | ns |
| TELAX | Address Hold Time | 50 |  | 50 |  | ns |
| TWLEH | Write Pulse Width ( $\bar{E}$ and $\bar{W}$ Low) | 300 |  | 350 |  | ns |
| TEHEL | Enable ( $\overline{\mathrm{E}}) \mathrm{Minimum} \mathrm{High} \mathrm{Time}$ | 120 | , | 150 |  | ns |
| TWLWH | Write Pulse Width ( $\bar{W}$ Low) | 300 |  | 350 |  | ns |
| TELEL | Read or Write Cycle Time | 420 |  | 500 |  | ns |
| TWHQX | Output Enable from Write ( $\bar{W}$ ) |  | 100 |  | 100 | ns |
| TELQX | Output Enable from Enable ( $\overline{\mathrm{E}})$ |  | 100 |  | 100 | ns |
| TEHQZ | Output Disable from Enable ( $\overline{\mathrm{E}}$ ) |  | 100 |  | 100 | ns |
| TWLQZ | Output Disable from Write ( $\overline{\mathrm{W}}$ ) |  | 100 |  | 100 | ns |
| TDVWH | Data Set-up Time | 200 |  | 250 |  | ns |
| TWHDZ | Data Hold Time | 0 |  | 0 |  | ns |
| TELWH | Write Pulse Width (E) and $\bar{W}$ Low) | 300 |  | 350 |  | ns |

## Write Cycle Waveforms



* Avoid bus contention

Read-Modify-Write Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6514-9, NMC6514-2 |  | NMC6514.5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 20 |  | 20 |  | ns |
| TELAX | Address Hold Time | 50 |  | 50 |  | ns |
| TELQV | Enable Access Time |  | 300 |  | 350 | ns |
| TAVQV | Address Access Time |  | 320 |  | 370 | ns |
| TWLQZ | Output Disable from Write ( $\overline{\mathrm{W}}$ ) |  | 100 |  | 100 | ns |
| TDVWH | Data Set-up Time | 200 |  | 250 |  | ns |
| TWHDX | Data Hold Time | 0 |  | 0 |  | ns |
| TWLEH | Write Pulse Width ( $\bar{W}$ and $\bar{E}$ Low) | 300 |  | 350 |  | ns |
| TQVWL | Data Valid to Write Time | 0 |  | 0 |  | ns |
| TWLWH | Write Pulse Width ( $\bar{W}$ Low) | 300 |  | 350 |  | ns |
| TELQX | Output Enable from Enable ( $\overline{\mathrm{E}}$ ) |  | 100 |  | 100 | ns |
| TEHEL | Enable ( $\overline{\mathrm{E}})$ Minimum High Time | 120 |  | 150 |  | ns |
| TWHEL | $\bar{W}$ Read Mode Set-up Time | 0 |  | 0 |  | ns |

## Read-Modify-Write Cycle Waveforms



* Avoid bus contention


## CMOS RAMs

## NMC6518 1024-Bit (1024 $\times 1$ ) Static RAM

## General Description

The NMC6518 is a static CMOS random access read/write memory organized as 1024 words of 1 bit each. This device is fabricated with National Semiconductor's silicon-gate CMOS technology and is fully compatible with the TTL en: vironment. Synchronous operation is provided by the onchip latches for the address inputs and data output. The ENABLE input serves as the device strobe controlling the latching functions. The TRI-STATE ${ }^{( }$output, in conjunction with the ENABLE input, allow easy memory expansion.

## Features

- Industry standard pinout
- Low data retention voltage - 2 V
- Low speed/power product
- TTL compatible - all inputs and outputs
- TRI-STATE ${ }^{\oplus}$ outputs for bus operation
- High output drive
- High noise immunity
- Military temperature range available
- On-chip address registers (latches)
- 18 pin - high density packaging.
- Output data latches


## Connection Diagram

Dual-In-Line Package


Order Number NMC6518J-2, NMC6518J-9 or NMC6518J. 5
See NS Package J16A
Order Number NMC6518N-5
See NS Package N16A
Pin Names

| A0-A9 | Address Inputs |
| :--- | :--- |
| $\overline{\mathrm{E}}$ | Chip Enable |
| $\bar{W}$ | Write Enable |
| D | Data Input |
| Q | Data Output |
| $\overline{\text { S1 }}, \overline{\text { S2 }}$ | Chip Selects |

Logic Symbol


## Functional Description

An NMC6518 memory cycle is initiated by the falling edge of the ENABLE input, which latches the address information into the on-chip registers. Data output is enabled when the WRITE $(\bar{W})$ input is high and the ENABLE, SEI.ECT $1(\overline{\mathrm{~S} 1})$ and SELECT $2(\overline{\mathrm{~S} 2})$ inputs are LOW.
When performing a read cycle a minimum ENABLE LOW time is required to assure valid data at the output. This minimum ENABLE LOW time is defined as the device enable access time. A minimum ENABLE HIGH time is required to return the columns to the HIGH state and to
precharge the sense amplifiers in preparation of the next cycle.
When performing a write cycle, the minimum ENABLE LOW time is required to enter new data. The write pulse is created by the coincident LOW of the WRITE, ENABLE and both SELECT inputs. The input data set-up and hold times are referenced to the rising edge of the WRITE, ENABLE, SELECT 1 or SELECT 2 inputs, whichever occurs first.

## Block Diagram



## Absolute Maximum Ratings

| Supply Voltage VCC | 7 V |
| :--- | ---: |
| Voltage at Any Pin | -0.3 V to $\mathrm{VCC}+0.3 \mathrm{~V}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Package Dissipation | 500 mW |
| Lead Temperature(Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ |


|  | Min | Max |
| :--- | ---: | ---: |
| Supply Voitage |  |  |
| NMC6518B-9 | 4.5 V | 5.5 V |
| NMC6518B-2 | 4.5 V | 5.5 V |
| NMC6518-9 | 4.5 V | 5.5 V |
| NMC6518-2 | 4.5 V | 5.5 V |
| NMC6518-5 | 4.75 V | 5.25 V |
| Temperature |  |  |
| NMC6518B-9 | $-40^{\circ} \mathrm{C}$ | $85^{\circ} \mathrm{C}$ |
| NMC6518B-2 | $-55^{\circ} \mathrm{C}$ | $125^{\circ} \mathrm{C}$ |
| NMC6518-9 | $-40^{\circ} \mathrm{C}$ | $85^{\circ} \mathrm{C}$ |
| NMC6518-2 | $-55^{\circ} \mathrm{C}$ | $125^{\circ} \mathrm{C}$ |
| NMC6518-5 | $0^{\circ} \mathrm{C}$ | $75^{\circ} \mathrm{C}$ |

DC Electrical Characteristics over the operating range, unless otherwise noted

| Symbol | Parameter | Conditions | NMC6518B-9, NMC6518B-2 <br> NMC6518-9, NMC6518-2 |  | NMC6518-5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Max | Min | Max |  |
| VCCDR | Data Retention Supply Voltage | $\mathrm{VI}=\mathrm{VCC}, \mathrm{GND}$ | 2.0 |  | 2.0 |  | V |
| ICCSB | Standby Supply Current |  |  | 10 |  | 100 | $\mu \mathrm{A}$ |
| ICCOP* | Operating Supply Current | $\begin{aligned} & \mathrm{f}=1 \mathrm{MHz}, \mathrm{IO}=0, \\ & \mathrm{VI}=\mathrm{VCC} \text { or } \mathrm{GND} \end{aligned}$ |  | 4 |  | 4 | mA |
| ICCDR | Data Retention Supply Current | $\begin{aligned} & \mathrm{VCC}=3.0 \mathrm{~V}, I \mathrm{O}=0, \\ & \mathrm{VI}=\mathrm{VCC} \text { or } \mathrm{GND} \end{aligned}$ |  | 10 |  | 100 | $\mu \mathrm{A}$ |
| II' | Input Leakage Current | $\mathrm{VI}=\mathrm{VCC}, \mathrm{GND}$ | -1.0 | +1.0 | -1.0 | +1.0 | $\mu \mathrm{A}$ |
| VIL | Input Low Voltage |  | -0.3 | 0.8 | -0.3 | 0.8 | V |
| VIH | Input High Voltage |  | VCC - 2.0 | $\mathrm{VCC}+0.3$ | VCC-2 | $\mathrm{VCC}+0.3$ | V |
| IOZ | Output Leakage Current | $\mathrm{VI}=\mathrm{VCC}, \mathrm{GND}$ | -1.0 | +1.0 | -1.0 | +1.0 | $\mu \mathrm{A}$ |
| VOL | Output Low Voltage | $\mathrm{IOL}=3.2 \mathrm{~mA}$ |  | 0.4 |  | 0.4 | V |
| VOH | Output High Voltage | $1 \mathrm{OH}=-0.4 \mathrm{~mA}$ | 2.4 |  | 2.4 |  | V |
| Cl | Input Capacitance | $\mathrm{f}=1 \mathrm{MHz}$ |  | 6 |  | 6 | pF |
| CO | Output Capacitance | $\mathrm{f}=1 \mathrm{MHz}$ |  | 10 |  | 10 | pF |

* ICCOP is proportional to operating frequency.


## AC Test Conditions

Input Rise and Fall Times: $\leq 20 \mathrm{~ns}$
All Timing Reference Levels: $1 / 2$ VCC
Output Load: 1 TTL Load, 50 pF
NMC6518 Bit Map and Address Decoding



Read Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6518B-9 <br> NMC6518B-2 |  | NMC6518-9 <br> NMC6518-2 |  | NMC6518.5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 0 |  | 0 |  | 10 |  | ns |
| TELAX | Address Hold Time | 40 |  | 50 |  | 50 |  | ns |
| TELQV | Enable Access Time |  | 180 |  | 250 |  | 300 | ns |
| TAVQV | Address Access Time |  | 180 |  | 250 |  | 310 | ns |
| TELEH | Enable (E) Minimum Low Time | 180 |  | 250 |  | 300 |  | ns |
| TELEL | Read or Write Cycle Time | 280 |  | 350 |  | 450 |  | ns |
| TEHEL | Enable (E) Minimum High Time | 100 |  | 100 |  | 150 |  | ns |
| TSHQX | Chip Select Output Disable Time |  | 120 |  | 160 |  | 200 | ns |
| TSLQX | Chip Select Output Enable Time |  | 120 |  | 160 |  | 200 | ns |

## Read Cycle Waveforms



## Write Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | $\begin{aligned} & \text { NMC6518B-9 } \\ & \text { NMC6518B-2 } \end{aligned}$ |  | $\begin{aligned} & \hline \text { NMC6518.9 } \\ & \text { NMC6518.2 } \\ & \hline \end{aligned}$ |  | NMC6518-5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 0 | . | 0 |  | 10 |  | ns |
| TELAX | Address Hold Time | 40 |  | 50 |  | 50 |  | ns |
| TWLWH | Write Pulse Width ( $\bar{W}$ Low) | 100 |  | 130 |  | 160 |  | ns |
| TELEL | Read or Write Cycle Time | 280 |  | 350 |  | 450 |  | ns |
| TWLSH | Chip Select Write Pulse Set-up Time | 100 |  | 130 |  | 160 |  | ns |
| TWLEH | Chip Enable Write Pulse Set-up Time | 100 |  | 130 |  | 160 | - | ns |
| TSLWH | Chip Select Write Pulse Hold Time | 100 |  | 130 |  | 160 |  | ns |
| TWHDX | Data Hold Time | 0 |  | 0 |  | 0 |  | ns |
| TDVWH | Data Set-up Time | 80 |  | 110 |  | 130 |  | ns |
| TEHEL | Enable (E) Minimum High Time | 100 |  | 100 |  | 150 |  | ns |
| TELEH | Enable (E) Minimum Low Time | 180 |  | 250 |  | 300 |  | ns |
| TELWH | Write Pulse Width (E and $\bar{W}$ Low) | 100 |  | 130 |  | 160 |  | ns |

## Write Cycle Waveforms


$0 \longrightarrow$ Hiz
*TWLWH, the write pulse, is coincidence low of $\overline{\mathrm{E}}, \overline{\mathrm{w}}, \overline{\mathrm{S} 1}$, and $\overline{\mathrm{S}}$ inputs

Read-Modify-Write Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6518B-9 <br> NMC6518B-2 |  | NMC6518.9 NMC6518-2 |  | NMC6518-5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 0 |  | 0 |  | 10 |  | ns |
| TELAX | Address Hold Time | $40^{\prime}$ |  | 50 |  | 50 |  | ns |
| TELQV | Enable Access Time |  | 180 |  | 250 |  | 300 | ns |
| TAVQV | Address Access Time |  | 180 |  | 250 |  | 310 | ns |
| TSHQX | Chip Select Output Disable Time |  | 120 |  | 160 |  | 200 | ns |
| TWLWH | Write Pulse Width ( $\bar{W}$ Low) | 100 |  | 130 |  | 160 |  | ns |
| TEHEL | Enable (E) Minimum High Time | 100 |  | 100 |  | 150 |  | ns |
| TWLSH | Chip Select Write Pulse Set-up Time | 100 |  | 130 |  | 160 |  | ns |
| TWLEH | Chip Enable Write Pulse Set-up Time | 100 |  | 130 |  | 160 |  | ns |
| TSLQX | Chip Select Output Enable Time |  | 120 |  | 160 |  | 200 | ns |
| TWHDX | Data Hold Time | 0 |  | 0 |  | 0 |  | ns |
| TDVWH | Data Set-up Time | 80 |  | 110 |  | 130 |  | ns |
| TWHQX | Output Enable from Write ( $\bar{W}$ ) |  | 120 |  | 160 |  | 200 | ns |
| TWLQZ | Output Disable from Write ( $\bar{W}$ ) |  | 120 |  | 160 |  | 200 | ns |

## Read-Modify-Write Cycle Waveforms



[^15]
## NMC6551 1024-Bit (256 $\times$ 4) Static RAM


#### Abstract

General Description The NMC6551 is a static CMOS random access read/write memory organized as 256 words of 4 bits each. This device is fabricated with National Semiconductor's silicon-gate CMOS technology and is fully compatible with the TTL environment. Synchronous operation is provided by on-chip address input and data output latches. The ENABLE input serves as the device strobe controlling the latching functions. The I/O terminals when not data output enabled, represent high impedance ports for easy memory expansion.


## Features

- Industry standard pinout
- Low data retention voltage - 2 V
- Low speed/power product
- TTL compatible - all inputs and outputs
- TRI-STATE ${ }^{\text {® }}$ outputs for bus operation
- High output drive
- High noise immunity
- Military temperature range available
- On-chip address registers (latches)
- 22 pin - high density packaging
- Output data latches
- Select latch for microprocessor interface


## Connection Diagram

Dual-In-Line Package


## Order Number NMC6551J-2, NMC6551J.9

 or NMC6551J.5See NS Package J22A
Order Number NMC6551N-5
See NS Package N22A

## Logic Symbol

Address Inputs
Chip Enable
Write Enable
Data Input
Data Output
Chip Selects


## Functional Description

An NMC6551 memory cycle is initiated by the falling edge of the ENABLE $(\overline{\mathrm{E}})$ input, which latches the ADDRESS and SELECT $2(\overline{\mathrm{~S} 2})$ information into the on-chip registers. Setup and hold times must be met. Data output is enabled when the WRITE $(\bar{W})$ input is HIGH and the ENABLE and SELECT 1 inputs are LOW.

When performing a read cycle a minimum ENABLE LOW time is required to assure valid data at the outputs. This minimum LOW time is defined as the device enable access time. A minimum ENABLE HIGH time is required to
return the columns to the HIGH state and to precharge the sense amplifiers in preparation of the next memory cycle.

When performing a write cycle, the minimum ENABLE LOW time is required to enter new data. The write pulse timing is created by the coincident LOW of the WRITE, ENABLE and SELECT 1 inputs. The data set-up and hold times are referenced to the rising edge of the WRITE, ENABLE, or SELECT 1 input, whichever occurs first.

Block Diagram


## Absolute Maximum Ratings

Supply Voltage VCC
Voltage at Any Pin
Storage Temperature Range
Package Dissipation
Lead Temperature(Soldering, 10 seconds)

7 V
-0.3 V to $\mathrm{VCC}+0.3 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$300^{\circ} \mathrm{C}$

Operating Range

|  | Min | Max |
| :--- | :---: | ---: |
| Supply Voltage |  |  |
| NMC6551B-9 | 4.5 V | 5.5 V |
| NMC6551B-2 | 4.5 V | 5.5 V |
| NMC6551-9 | 4.5 V | 5.5 V |
| NMC6551-2 | 4.5 V | 5.5 V |
| NMC6551-5 | 4.75 V | 5.25 V |
| Temperature |  |  |
| NMC6551B-9 | $-40^{\circ} \mathrm{C}$ | $85^{\circ} \mathrm{C}$ |
| NMC6551B-2 | $-55^{\circ} \mathrm{C}$ | $125^{\circ} \mathrm{C}$ |
| NMC6551-9 | $-40^{\circ} \mathrm{C}$ | $85^{\circ} \mathrm{C}$ |
| NMC6551-2 | $-55^{\circ} \mathrm{C}$ | $125^{\circ} \mathrm{C}$ |
| NMC6551-5 | $0^{\circ} \mathrm{C}$ | $75^{\circ} \mathrm{C}$ |

DC Electrical Characteristics over the operating range, unless otherwise noted

| Symbol | Parameter | Conditions | NMC6551B-9, NMC6551B-2 <br> NMC6551-9, NMC6551-2 |  | NMC6551-5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Max | Min | Max |  |
| VCCDR | Data Retention Supply Voltage | $\mathrm{VI}=\mathrm{VCC}, \mathrm{GND}$ | 2.0 |  | 2.0 |  | V |
| ICCSB | Standby Supply Current |  |  | $\begin{gathered} 10 \\ 1\left(+25^{\circ} \mathrm{C}\right) \end{gathered}$ |  | 100 | $\mu \mathrm{A}$ |
| ICCOP* | Operating Supply Current | $\begin{aligned} & f=1 \mathrm{MHz}, I O=0, \\ & V I=V C C \text { or } G N D \end{aligned}$ |  | 4 |  | 4 | mA |
| ICCDR | Data Retention Supply Current | $\begin{aligned} & \mathrm{VCC}=3.0 \mathrm{~V}, \mathrm{IO}=0, \\ & \mathrm{VI}=\mathrm{VCC} \text { or } \mathrm{GND} \end{aligned}$ |  | 10 |  | 100 | $\mu \mathrm{A}$ |
| II | Input Leakage Current | $V I=V C C, G N D$ | -1.0 | +1.0 | -1.0 | +1.0 | $\mu \mathrm{A}$ |
| VIL | Input Low Voltage |  | -0.3 | 0.8 | -0.3 | 0.8 | V |
| VIH | Input High Voltage |  | VCC - 2.0 | VCC +0.3 | VCC-2 | $\mathrm{VCC}+0.3$ | V |
| IOZ | Output Leakage Current | $\mathrm{VI}=\mathrm{VCC}, \mathrm{GND}$ | -1.0 | +1.0 | -1.0 | +1.0 | $\mu \mathrm{A}$ |
| VOL | Output Low Voltage | $1 \mathrm{OL}=3.2 \mathrm{~mA}$ |  | 0.4 |  | 0.4 | V |
| VOH | Output High Voltage | $1 \mathrm{OH}=-0.4 \mathrm{~mA}$ | 2.4 |  | 2.4 |  | V |
| Cl | Input Capacitance | $\mathrm{f}=1 \mathrm{MHz}$ |  | 6 |  | 6 | pF |
| CO | Output Capacitance | $\mathrm{f}=1 \mathrm{MHz}$ |  | 10 |  | 10. | pF |

* ICCOP is proportional to operating frequency.


## AC Test Conditions

Input Rise and Fall Times: $\leq 20 \mathrm{~ns}$
All Timing Reference Levels: $1 / 2 \mathrm{VCC}$
Output Load: 1 TTL Load, 50 pF
NMC6551 Bit Map and Address Decoding


Read Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | $\begin{aligned} & \text { NMC6551B-9 } \\ & \text { NMC6551B-2 } \\ & \hline \end{aligned}$ |  | $\begin{aligned} & \text { NMC6551.9 } \\ & \text { NMC6551.2 } \end{aligned}$ |  | NMC6551.5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 0 |  | 0 |  | 10 |  | ns |
| TELAX | Address Hold Time | 40 |  | 50 |  | 70 |  | ns |
| TELQV | Enable Access Time |  | 220 |  | 300 |  | 350 | ns |
| TAVQV | Address Access Time |  | 220 |  | 300 |  | 360 | ns |
| TELEH | Enable (E) Minimum Low Time | 220 |  | 300 |  | 350 |  | ns |
| TELS2X | Chip Select 2 Hold Time | 40 |  | 50 |  | 70 |  | ns |
| TEHEL | Enable (E) Minimum High Time | 100 |  | 100 |  | 150 |  | ns |
| TELEL | Read or Write Cycle Time | 320 |  | 400 |  | 500 |  | ns |
| TS1LQX | Chip Select 1 Output Enable Time |  | 130 |  | 150 |  | 180 | ns |
| TS1HQZ | Chip Select 1 Output Disable Time |  | 130 |  | 150 |  | 180 | ns |
| TS2LEL | Chip Select 2 Set-up Time | 0 |  | 0 |  | 10 |  | ns |

## Read Cycle Waveforms



## Write Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6551B-9 <br> NMC6551B-2 |  | NMC6551-9 <br> NMC6551-2 |  | NMC6551-5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max | Min | Max |  |
| TAVEL | Address Set-up.Time | 0 |  | 0 |  | 10 |  | ns |
| TELAX | Address Hold Time | 40 |  | 50 |  | 70 |  | ns |
| TWLWH | Write Pulse Width ( $\bar{W}$ Low) | 120 |  | 180 |  | 210 |  | ns |
| TELEL | Read or Write Cycle Time | 320 |  | 400 |  | 500 |  | ns |
| TELEH | Enable (E) Minimum Low Time | 220 |  | 300 |  | 350 |  | ns |
| TS2LEL | Chip Select 2 Set-up Time | 0 |  | 0 |  | 10 |  | ns |
| TWHDX | Data Hold Time | 0 |  | 0 |  | 0 |  | ns |
| TELS2X | Chip Select 2 Hold Time | 40 |  | 50 |  | 70 |  | ns |
| TDVWH | Data Set-up Time | 100 |  | 150 |  | 170 |  | ns |
| TELWH | Write Pulse Width ( $\bar{E}$ and $\bar{W}$ Low) | 120 |  | 180 |  | 210 |  | ns |
| TEHEL | Enable (E) Minimum High Time | 100 |  | 100 |  | 150 |  | ns |
| TWLEH | Write Pulse Width (E and $\bar{W}$ Low) | 120 |  | 180 |  | 210 |  | ns |
| TS1LWH | Chip Select 1 Write Pulse Hold Time | 120 |  | 180 |  | 210 |  | ns |
| TWLS1H | Chip Select 1 Write Pulse Set-up Time | 120 |  | 180 |  | 210 |  | ns |
| TS1LQX | Output Enable from $\overline{\mathrm{S} 1}$ |  | 130 |  | 150 |  | 180 | ns |
| TWLQZ | Output Disable from $\bar{W}$ |  | 130 |  | 150 |  | 180 | ns |
| TWHQX | Output Enable from $\bar{W}$ |  | 130 |  | 150 |  | 180 | ns |
| TEHQZ | Output Disable from $\bar{E}$ |  | 130 |  | 150 |  | 180 | ns |

## Write Cycle Waveforms



[^16]Read-Modify-Write Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6551B-9 NMC6551B-2 |  | $\begin{aligned} & \text { NMC6551-9 } \\ & \text { NMC6551-2 } \\ & \hline \end{aligned}$ |  | NMC6551-5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 0 |  | 0 |  | 10 |  | ns |
| TELAX | Address Hold Time | 40 |  | 50 |  | 70 |  | ns |
| TELQV | Enable Access Time |  | 220 |  | 300 |  | 350 | ns |
| TAVQV | Address Access Time |  | 220 |  | 300 |  | 360 | ns |
| TWLEH | Write Pulse Width ( $\bar{W}$ and $\bar{E}$ Low) | 120 |  | 180 |  | 210 |  | ns |
| TEHEL | Enable (E) Minimum High Time | 100 |  | 100 |  | 150 |  | ns |
| TWLWH | Write Pulse Width ( $\bar{W}$ Low) | 120 |  | 180 |  | 210 |  | ns |
| TELEL | Read or Write Cycle Time | 320 |  | 400 |  | 500 |  | ns |
| TS1LQX | Chip Select 1 Output Enable Time |  | 130 |  | 150 |  | 180 | ns |
| TS1HQZ | Chip Select 1 Output Disable Time |  | 130 |  | 150 |  | 180 | ns |
| TS2LEL | Chip Select 2 Set-up Time | 0 |  | 0 |  | 10 |  | ns |
| TWHDX | Data Hold Time | 0 |  | 0 |  | 0 |  | ns |
| TELS2H | Chip Select 2 Hold Time | 40 |  | 50 |  | 70 |  | ns |
| TWLS1H | Chip Select 1 Write Pulse Set-up Time | 120 |  | 180 |  | 210 |  | ns |
| TWLQZ | Output Disable from Write ( $\bar{W}$ ) |  | 130 |  | 150 |  | 180 | ns |
| TDVWH | Data Set-up Time | 100 |  | 150 |  | 170 |  | ns |
| TQVWL | Data Valid to Write Time | 0 |  | 0 |  | 0 |  | ns |
| TWHEL | $\bar{W}$ Read Mode Set-up Time | 0 |  | 0 |  | 0 |  | ns |
| TWHQX | Output Enable from Write ( $\bar{W}$ ) |  | 130 |  | 150 |  | 180 | ns |

Read-Modify-Write Cycle Waveforms


## NMC6552 1024-Bit (256 $\times$ 4) Static RAM

## General Description

The NMC6552 is a static CMOS random access read/write memory organized as 256 words of 4 bits each. This device is fabricated with National Semiconductor's silicon-gate CMOS technology and is fully compatible with the TTL environment. Synchronous operation is provided by the onchip address input and data output registers. The ENABLE input serves as the device strobe controlling the latching functions. The data I/O terminals, when not output data enabled, represent a high impedance for easy memory expansion.

## Features

Low data retention voltage - 2 V

- Low speed/power product
- TTL compatible - all inputs and outputs
- TRI-STATE ${ }^{\oplus}$ outputs for bus operation
- High output drive
- High noise immunity
- Military temperature range available
- On-chip address registers (latches)
- Common I/O - high density packaging
- Output data latches
- Select latch for microprocessor interface


## Connection Diagram

## Dual-In-Line Package



Order Number NMC6552J-2, NMC6552J-9
or NMC6552J. 5
See NS Package J18A
Order Number NMC6552N-5 See NS Package N18A

Pin Names

| A0-A7 | Address Inputs |
| :--- | :--- |
| $\overline{\mathrm{E}}$ | Chip Enable |
| $\bar{W}$ | Write Enable |
| DQ0-DQ3 | Data In/Out |
| $\overline{\mathrm{S} 1, \overline{\text { S2 }}}$ | Chip Selects |

## Functional Description

An NMC6552 memory cycle is initiated by the falling edge of the ENABLE ( $\bar{E})$ input, which latches the ADDRESS and SELECT $2(\overline{\mathrm{~S} 2})$ information into the on-chip registers. The output data latches are transparent when the ENABLE input is LOW, allowing the state of the memory to be presented to the output buffers. The output buffers are enabled when the WRITE $(\bar{W})$ input is HIGH, and the SELECT 1 ( $\overline{\mathrm{S} 1}$ ) input is LOW.
When performing a read cycle, a minimum ENABLE LOW time is required to assure valid data at the device outputs. This minimum LOW time is defined as the enable access time. A minimum ENABLE HIGH time is required
to return the columns to the HIGH state and to precharge the sense amplifiers in preparation of the next cycle. The data is latched with the rising edge of the ENABLE input, allowing maintenance of output data until the SELECT 1 input goes HIGH.
When performing a write cycle, a minimum ENABLE LOW time is required for new data entry. The write pulse timing is defined by the coincident LOW of the WRITE, ENABLE and SELECT 1 inputs. The input data set-up and hold times are referenced to the rising edge of the WRITE, ENABLE, or SELECT 1 inputs, whichever occurs first.

## Block Diagram



## Absolute Maximum Ratings

|  |  |  | Min | Max |
| :---: | :---: | :---: | :---: | :---: |
| Supply Voltage VCC | 7 V | Supply Voltage |  |  |
| Voltage at Any Pin | -0.3 V to $\mathrm{VCC}+0.3 \mathrm{~V}$ | NMC6552B-9 | 4.5V | 5.5 V |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ | NMC6552B-2 | 4.5 V | 5.5 V |
| Package Dissipation | 500 mW | NMC6552-9 | 4.5 V | 5.5 V |
| Lead Temperature(Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ | NMC6552.5 | 4.75 V | 5.25 V |
| Temperature |  |  |  |  |
|  |  | NMC6552B-9 | $-40^{\circ} \mathrm{C}$ | $85^{\circ} \mathrm{C}$ |
|  |  | NMC6552B-2 | $-55^{\circ} \mathrm{C}$ | $125^{\circ} \mathrm{C}$ |
|  |  | NMC6552-9 | $-40^{\circ} \mathrm{C}$ | $85^{\circ} \mathrm{C}$ |
| , |  | NMC6552-2 | $-55^{\circ} \mathrm{C}$ | $125^{\circ} \mathrm{C}$ |
| (Electral Cha |  | NMC6552-5 | $0^{\circ} \mathrm{C}$ | $75^{\circ} \mathrm{C}$ |

DC Electrical Characteristics over the operating range, unless otherwise noted

| Symbol | Parameter | Conditions | NMC6552B-9, NMC6552B-2NMC6552-9, NMC6552-2 |  | NMC6552-5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Max | Min | Max |  |
| VCCDR | Data Retention Supply Voltage | $\mathrm{VI}=\mathrm{VCC}, \mathrm{GND}$ | 2.0 |  | 2.0 |  | V |
| ICCSB | Standby Supply Current |  |  | $\begin{gathered} 10 \\ 1\left(+25^{\circ} \mathrm{C}\right) \end{gathered}$ |  | 100 | $\mu \mathrm{A}$ |
| ICCOP* | Operating Supply Current | $\begin{aligned} & f=1 \mathrm{MHz}, \mathrm{IO}=0, \\ & \mathrm{VI}=\mathrm{VCC} \text { or } \mathrm{GND} \end{aligned}$ |  | 4 |  | 4 | mA |
| ICCDR | Data Retention Supply Current | $\begin{aligned} & \mathrm{VCC}=3.0 \mathrm{~V}, \mathrm{IO}=0 \\ & \mathrm{VI}=\mathrm{VCC} \text { or } \mathrm{GND} \end{aligned}$ |  | 10 |  | 100 | $\mu \mathrm{A}$ |
| 11 | Input Leakage Current | $\mathrm{VI}=\mathrm{VCC}, \mathrm{GND}$ | -1.0 | +1.0 | -1.0 | +1.0 | $\mu \mathrm{A}$ |
| VIL | Input Low Voltage |  | -0.3 | 0.8 | -0.3 | 0.8 | V |
| VIH | Input High Voltage |  | VCC-2.0 | VCC +0.3 | VCC-2 | $\mathrm{VCC}+0.3$ | V |
| 102 | Output Leakage Current | $\mathrm{VI}=\mathrm{VCC}, \mathrm{GND}$ | -1.0 | +1.0 | -1.0 | +1.0 | $\mu \mathrm{A}$ |
| VOL | Output Low Voltage | $\mathrm{IOL}=3.2 \mathrm{~mA}$ |  | 0.4 |  | 0.4 | V |
| VOH | Output High Voltage | $1 \mathrm{OH}=-0.4 \mathrm{~mA}$ | 2.4 |  | 2.4 |  | V |
| Cl | Input Capacitance | $\mathrm{f}=1 \mathrm{MHz}$ |  | 6 |  | 6 | pF |
| CO | Output Capacitance | $\mathrm{f}=1 \mathrm{MHz}$ |  | 10 |  | 10 | pF |

* ICCOP is proportional to operating frequency.


## AC Test Conditions

Input Rise and Fall Times: $\leq 20$ ns
All Timing Reference Levels: $1 / 2 \mathrm{VCC}$
Output Load: 1 TTL Load, 50 pF

## NMC6552 Bit Map and Address Decoding


(MSB) A7 COLUMN AG (SB) A5

Read Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6552B.9 NMC6552B-2 |  | NMC6552.9 <br> NMC6552-2 |  | NMC6552-5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 0 |  | 0 |  | 10 |  | ns |
| TELAX | Address Hold Time | 40 |  | 50 |  | 70 |  | ns |
| TELQV | Enable Access Time |  | 220 |  | 300 |  | 350 | ns |
| TAVQV | Address Access Time |  | 220 |  | 300 |  | 360 | ns |
| TELEH | Enable (E) Minimum Low Time | 220 |  | 300 |  | 350 |  | ns |
| TELS2X | Chip Select 2 Hold Time | 40 |  | 50 |  | 70 |  | ns |
| TEHEL | Enable ( $\overline{\mathrm{E}}$ ) Minimum High Time | 100 |  | 100 |  | 150 |  | ns |
| TELEL | Read or Write Cycle Time | 320 |  | 400 |  | 500 |  | ns |
| TS1LQX | Chip Select 1 Output Enable Time |  | 130 |  | 150 |  | 180 | ns |
| TS1HQZ | Chip Select 1 Output Disable Time |  | 130 |  | 150 |  | 180 | ns |
| TS2LEL | Chip Select 2 Set-up Time | 0 |  | 0 |  | 10 |  | ns |

## Read Cycle Waveforms



Write Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6552B-9 <br> NMC6552B-2 |  | NMC6552-9 <br> NMC6552-2 |  | NMC6552-5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max | Min | Max |  |
| TAVEL | Address Set-up Time | 0 |  | 0 |  | 10 |  | ns |
| TELAX | Address Hold Time | 40 |  | 50 |  | 70 |  | ns |
| TS2LEL | Chip Select 2 Set-up Time | 0 |  | 0 |  | 10 |  | ns |
| TWHDX | Data Hold Time | 0 |  | 0 |  | 0 |  | ns |
| TELEH | Enable (E) Minimum Low Time | 220 |  | 300 |  | 350 |  | ns |
| TWLWH | Write Pulse Width ( $\bar{W}$ Low) | 120 |  | 180 |  | 210 |  | ns |
| TELEL | Read or Write Cycle Time | 320 |  | 400 |  | 500 |  | ns |
| TEHEL | Enable (E) Minimum High Time | 100 |  | 100 |  | 150 |  | ns |
| TDVWH | Data Set-up Time | 100 |  | 150 |  | 170 |  | ns |
| TELWH | Write Pulse Width (E and $\bar{W}$ Low) | 120 |  | 180 |  | 210 |  | ns |
| TWLEH | Write Pulse Width ( $\bar{W}$ and $\bar{E}$ Low) | 120 |  | 180 |  | 210 |  | ns |
| TELS2H | Chip Select 2 Hold Time | 40 |  | 50 |  | 70 |  | ns |
| TWLS1H | Chip Select 1 Write Pulse Set-up Time | 120 |  | 180 |  | 210 |  | ns |
| TS1LWL | Chip Select 1 Write Pulse Hold Time | 120 |  | 180 |  | 210 |  | ns |

## Write Cycle Waveforms



* TWLWH, the write pulse, is the coincidence low of $\bar{E}, \bar{W}$, and $\bar{S} 1$ inputs

Read-Modify-Write Cycle AC Electrical Characteristics over the operating range

| Symbol | Parameter | NMC6552B. 9 <br> NMC6552B. 2 |  | NMC6552.9 <br> NMC6552.2 |  | NMC6552.5 |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max | Min | Max |  |
| tavel | Address Set-up Time | 0 |  | 0 |  | 10 |  | ns |
| telax | Address Hold Time | 40 |  | 50 |  | 70 |  | ns |
| telqv | Enable Access Time |  | 220 |  | 300 |  | 350 | ns |
| tavav | Address Access Time |  | 220 |  | 300 |  | 360 | ns |
| TS2LEL | Chip Select 2 Set-up Time | 0 |  | 0 |  | 10 |  | ns |
| TWHDX | Data Hold Time | 0 |  | 0 |  | 0 |  | ns |
| TELS2X | Chip Select 2 Hold Time | 40 |  | 50 |  | 70 |  | ns |
| TWLS1H | Chip Select 1 Write Pulse Set-up Time | 120 |  | 180 |  | 210 |  | ns |
| TS1LQX | Chip Select 1 Output Enable Time |  | 130 |  | 150 |  | 180 | n's |
| TDVWH | Data Set-up Time | 100 |  | 150 |  | 170 |  | ns |
| TWLEH | Write Pulse Width ( $\bar{W}$ and $\bar{E}$ Low) | 120 |  | 180 |  | 210 |  | ns |
| TQVWL | Data Valid to Write Time | 0 |  | 0 |  | 0 |  | ns |
| TWLWH | Write Pulse Width ( $\bar{W}$ Low) | 120 |  | 180 |  | 210 |  | ns |
| TEHEL | Enable (E) Minimum High Time | 100 |  | 100 |  | 150 |  | ns |
| TQVWL | Data Valid to Write Time | 0 |  | 0 |  | 0 |  | ns |
| twhax | Output Enable from Write ( $\bar{W}$ ) |  | 130 |  | 150 |  | 180 | ns |
| TWLQZ | Output Disable from Write ( $\bar{W}$ ) |  | 130 |  | 150 |  | 180 | ns |

Read-Modify-Write Cycle Waveforms


[^17]
## Section 5

## CD4XXX Series Logic

## General Description

The CD4000M/CD4000C is a monolithic complementary MOS (CMOS) dual 2 -input NOR gate plus an inverter. Nand P-channel enhancement mode transistors provide a symmetrical circuit with output swings essentially equal to the supply voltage. This results in high noise immunity over a wide supply voltage range. No DC power other than that caused by leakage current is consumed during static conditions. All inputs are protected against static discharge and latching conditions.

Features

- Wide supply voltage range 3.0 V to 15 V
- Low power

10 nW (typ.)

- High noise immunity


## CD4000M/CD4000C Dual 3-Input NOR Gate Plus Inverter

## Schematic and Connection Diagram



Absolute Maximum Ratings (Note 1)

Voltage at Any Pin
Operating Temperature Range CD4000M CD4000C
Storage Temperature Range
Package Dissipation
Operating $\mathrm{V}_{\mathrm{DD}}$ Range
Lead Temperature (Soldering, 10 seconds)
$V_{S S}-0.3 V$ to $V_{D D}+0.3 V$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$\mathrm{V}_{\mathrm{SS}}+3 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{SS}}+15 \mathrm{~V}$
$300^{\circ} \mathrm{C}$

DC Electrical Characteristics CD4000M (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| $I_{\text {DD }}$ | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.05 \\ & 0.1 \end{aligned}$ |  |  | $\begin{aligned} & 0.05 \\ & 0.1 \end{aligned}$ |  | $\begin{aligned} & 3 \\ & 6 \end{aligned}$ | $\mu \mathrm{A}$ $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ |  |  | 0.05 0.05 |  | 0.05 0.05 | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ |  | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ |  |  |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {NL }}$ | Noise Immunity (Note 3) | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, \quad V_{O}=1.4 \mathrm{~V} \text { or } 3.6 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=2.8 \mathrm{~V} \text { or } 7.2 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ |  |  | $\begin{aligned} & 1.4 \\ & 2.9 \end{aligned}$ |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{NH}}$ | Noise Immunity (Note 3) | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, \quad V_{O}=1.4 \mathrm{~V} \text { or } 3.6 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{\mathrm{O}}=2.8 \mathrm{~V} \text { or } 7.2 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 1.4 \\ & 2.9 \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ |  |  | 1.5 3.0 |  | $\begin{aligned} & v \\ & v \end{aligned}$ |
| IDN | Low Level Output Current | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 0.5 \\ 1.1 \end{gathered}$ |  | $\begin{aligned} & 0.4 \\ & 0.9 \end{aligned}$ |  |  | 0.28 0.65 |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $I_{\text {DP }}$ | High Level Output Current | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, \quad V_{O}=2.5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & -0.62 \\ & -0.62 \end{aligned}$ |  | -0.5 |  |  | -0.35 -0.35 |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| 1 IN | Input Current | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V} \end{aligned}$ | -1.0 | 1.0 | -0.1 | $\begin{array}{r} -10^{-5} \\ 10^{-5} \end{array}$ | 0.1 | -1.0 | 1.0 | $\mu \mathrm{A}$ $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: For the NOR gates $V_{N H}$ and $V_{N L}$ are tested at each input while all other inpuits are at $V_{\text {SS }}$.
Note 4: CPD determines the no load AC power consumption of y $Y$ CMOS device. For explanation see 54C/74C Family Characteristics application note, AN-90.

AC Electrical Characteristics CD4000M $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted

| PARAMETER |  | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ${ }_{\text {tPHL }}$ | Propagation Delay Time, High to Low Level | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 40 \\ & 20 \end{aligned}$ | $\begin{aligned} & 50 \\ & 40 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {PLH }}$ | Propagation Delay Time, Low to High Level | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{aligned} & 95 \\ & 45 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| ${ }^{\text {t }}$ THL | Transition Time, High to Low Level | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 20 \end{aligned}$ | $\begin{aligned} & 125 \\ & 70 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| ${ }^{\text {t tib }}$ | Transition Time, Low to High Level | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 70 \\ & 35 \end{aligned}$ | $\begin{aligned} & 175 \\ & 75 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $C_{1}$ | Input Capacitance | Any Input |  | 5 | , | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 4) |  | 35 |  | pF |

## DC Electrical Characteristics C4000C (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.5 \\ & 5 \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 5 \end{aligned}$ |  | $\begin{aligned} & 15 \\ & 30 \end{aligned}$ | $\mu \mathrm{A}$ $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {OL }}$ | Low Level Output Voltage | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ |  |  | 0.05 0.05 |  | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ | v |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ |  | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ |  |  | 4.95 9.95 |  | v |
| $\mathrm{V}_{\text {NL }}$ | Noise Immunity (Note 3) | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, \quad V_{O}=1.4 \mathrm{~V} \text { or } 3.6 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=2.8 \mathrm{~V} \text { or } 7.2 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ |  |  | $\begin{aligned} & 1.4 \\ & 2.9 \end{aligned}$ |  | v |
| $\mathrm{V}_{\mathrm{NH}}$ | Noise Immunity (Note 3) | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, \quad V_{O}=1.4 \mathrm{~V} \text { or } 3.6 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=2.8 \mathrm{~V} \text { or } 7.2 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 1.4 \\ & 2.9 \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ |  |  | 1.5 3.0 |  | V |
| $I_{\text {DN }}$ | Low Level Output Current | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 0.35 \\ & 0.72 \end{aligned}$ |  | $\begin{aligned} & 0.3 \\ & 0.6 \end{aligned}$ |  |  | 0.24 0.48 |  | mA |
| IDP | High Level Output Current | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, \quad V_{O}=2.5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V} \end{aligned}$ | $\begin{array}{\|l} -0.35 \\ -0.3 \end{array}$ |  | $\begin{aligned} & -0.3 \\ & -0.25 \end{aligned}$ |  |  | $\begin{aligned} & -0.24 \\ & -0.2 \end{aligned}$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $\mathrm{i}_{\text {IN }}$ | Input Current | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V} \end{aligned}$ | -0.3 | 0.3 | -0.3 | $\begin{array}{r} -10^{-5} \\ 10^{-5} \end{array}$ | 0.1 | -1.0 | 1.0 | $\mu \mathrm{A}$ $\mu \mathrm{A}$ |

AC Electrical Characteristics $C D 4000 \mathrm{C} T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted

| PARAMETER |  | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {PHL }}$ | Propagation Delay Time, High to Low Level | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 40 \\ & 20 \end{aligned}$ | $\begin{aligned} & 80 \\ & 55 \end{aligned}$ | ns |
| $t_{\text {PLH }}$ | Propagation Delay Time, Low to High Level | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{aligned} & 120 \\ & 65 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| ttic | Transition Time, High to Low Level | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 20 \end{aligned}$ | $\begin{aligned} & 200 \\ & 115 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| ${ }^{\text {tTLH }}$ | Transition Time, Low to High Level | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 70 \\ & 35 \end{aligned}$ | $\begin{aligned} & 300 \\ & 125 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $C_{1}$ | Input Capacitance | Any Input |  | 5 |  | pF |
| CPD | Power Dissipation Capacitance | (Note 4) |  | 35 |  | pF |

## CD4001M/CD4001C Quadruple 2-Input NOR Gate CD4011M/CD4011C Quadruple 2-Input NAND Gate

## General Description

The CD4001M/CD4001C, CD4011M/CD4011C are monolithic complementary MOS (CMOS) quadruple two-input NOR and NAND gate integrated circuits. N- and Pchannel enhancement mode transistors provide a symmetrical circuit with output swings essentially equal to the supply voltage. This results in high noise immunity over a wide supply voltage range. No DC power other than that caused by leakage current is consumed during static conditions. All inputs are protected against static discharge and latching conditions.

## Features

| Wide supply voltage range | 3.0 V to 15 V |
| :--- | ---: |
| Low power | 10 nW (typ.) |
| - High noise immunity | $0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.) |

## Connection Diagrams



TOP VIEW


# Absolute Maximum Ratings <br> (Note 1) 

Voltage an Any Pin $\quad V_{S S}-0.3 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{DD}}+0.3 \mathrm{~V}$
Operating Temperature Range CD4001M, CD4011M
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ CD4001C, CD4011C $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

Storage Temperature Range Package Dissipation
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW $\begin{array}{lr}\text { Operating } V_{D D} \text { Range } & V_{S S}+3.0 \mathrm{~V} \text { to } V_{S S}+15 \mathrm{~V} \\ \text { Lead Temperature (Soldering, } 10 \text { seconds) } & 300^{\circ} \mathrm{C}\end{array}$

## DC Electrical Characteristics - CD4001M, CD4011M

| Parameter |  | Conditions | Limits |  |  |  |  |  |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $-55^{\circ} \mathrm{C}$ | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| $\mathrm{I}_{\mathrm{L}}$ | Quiescent Device |  | $V_{D D}=5.0 \mathrm{~V}$ |  | 0.05 |  | 0.001 | 0.05 |  | 3.0 | $\mu \mathrm{A}$ |
|  | Current |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.1 |  | 0.001 | 0.1 |  | 6.0 | $\mu \mathrm{A}$ |
| $P_{D}$ | Quiescent Device | $V_{D D}=5.0 \mathrm{~V}$ |  | 0.25 |  | 0.005 | 0.25 |  | 15 | $\mu \mathrm{W}$ |
|  | Dissipation/Package | $V_{D D}=10 \mathrm{~V}$ |  | 1.0 |  | 0.01 | 1.0 |  | 60 | $\mu \mathrm{W}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Output Voltage Low | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{1}=V_{D D}, l_{0}=0 \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | Level | $V_{D D}=10 \mathrm{~V}, V_{I}=V_{D D}, I_{O}=0 \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Voltage High | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{1}=V_{S S}, l_{0}=0 \mathrm{~A}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  | Level | $V_{D D}=10 \mathrm{~V}, V_{1}=V_{S S}, l_{0}=0 \mathrm{~A}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
| $V_{N L}$ | Noise Immunity | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=3.6 \mathrm{~V}, \mathrm{l}_{0}=0 \mathrm{~A}$ | 1.5 |  | 1.5 | 2.25 |  | 1.4 |  | V |
|  | (All Inputs) | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=7.2 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A}$ | 3.0 |  | 3.0 | 4.5 |  | 2.9 |  | V |
| $\mathrm{V}_{\mathrm{NH}}$ | Noise Immunity | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.95 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A}$ | 1.4 |  | 1.5 | 2.25 |  | 1.5 |  | V |
|  | (All Inputs) | $\mathrm{V}_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=2.9 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A}$ | 2.9 |  | 3.0 | 4.5 |  | 3.0 |  | V |
| $I_{D} N$ | Output Drive Current | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{\mathrm{DD}}$ | 0.5 |  | 0.40 | 1.0 |  | 0.28 |  | mA |
|  | N-Channel (4001) | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}, V_{I}=V_{D D}$ | 1.1 |  | 0.9 | 2.5 |  | 0.65 |  | mA |
| $I_{D} P$ | Output Drive Current | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=2.5 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{S S}$ | -0.62 |  | -0.5 | -2.0 |  | -0.35 |  | mA |
|  | P-Channel (4001) | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}, V_{I}=V_{S S}$ | -0.62 |  | -0.5 | -1.0 |  | -0.35 |  | mA |
| $I_{0} \mathrm{~N}$ | Output Drive Current | $V_{D D}=5.0 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}, V_{1}=V_{D D}$ | 0.31 |  | 0.25 | 0.5 |  | 0.175 |  | mA |
|  | N-Channel (4011) | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}, V_{I}=V_{D D}$ | 0.63 |  | 0.5 | 0.6 |  | 0.35 |  | mA |
| $I_{D} P$ | Output Drive Current | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=2.5 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{S S}$ | -0.31 |  | -0.25 | -0.5 |  | -0.175 |  | mA |
|  | P-Channel (4011) | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{S S}$ | -0.75 |  | -0.6 | -1.2 |  | -0.4 |  | mA |
| 1 | Input Current |  |  |  |  | 10 |  |  |  | pA |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for
"Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of
"Electrical Characteristics" provides conditions for actual device operation.

| Parameter |  | Conditions | Limits |  |  |  |  |  |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $-40^{\circ} \mathrm{C}$ | $25^{\circ} \mathrm{C}$ |  |  | $80^{\circ} \mathrm{C}$ |  |  |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| $I_{L}$ | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.5 \\ & 5.0 \end{aligned}$ |  | $\begin{aligned} & 0.005 \\ & 0.005 \end{aligned}$ | $\begin{aligned} & 0.5 \\ & 5.0 \end{aligned}$ |  | $\begin{aligned} & 15 \\ & 30 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |
| $P_{\text {D }}$ | Quiescent Device Dissipation/Package |  | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 2.5 \\ & 50 \end{aligned}$ |  | $\begin{gathered} 0.025 \\ 0.05 \end{gathered}$ | $\begin{aligned} & 2.5 \\ & 50 \end{aligned}$ |  | $\begin{gathered} 75 \\ 300 \end{gathered}$ | $\begin{aligned} & \mu W \\ & \mu W \end{aligned}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Output Voltage Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{1}=V_{D D}, I_{O}=0 \mathrm{~A} \\ & V_{D D}=10 \mathrm{~V}, V_{I}=V_{D D}, I_{O}=0 A \end{aligned}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ |  | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Voltage High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{1}=V_{S S}, I_{O}=0 A \\ & V_{D D}=10 \mathrm{~V}, V_{I}=V_{S S}, I_{O}=0 A \end{aligned}$ | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ |  | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ | $\begin{gathered} 5.0 \\ 10 \end{gathered}$ |  | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ |  | $\begin{aligned} & \text { V } \\ & \mathrm{V} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{NL}}$ | Noise Immunity (All Inputs) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=3.6 \mathrm{~V}, I_{O}=0 \mathrm{~A} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=7.2 \mathrm{~V}, I_{O}=0 \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ | 2.25 4.5 |  | $\begin{aligned} & 1.4 \\ & 2.9 \end{aligned}$ |  | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{V}_{\mathrm{NH}}$ | Noise Immunity (All Inputs) | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.95 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=2.9 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 1.4 \\ & 2.9 \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ | $\begin{gathered} 2.25 \\ 4.5 \end{gathered}$ |  | 1.5 3.0 |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{I}_{\mathrm{D}} \mathrm{N}$ | Output Drive Current N-Channel (4001) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}, V_{1}=V_{D D} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}, V_{1}=V_{D D} \end{aligned}$ | $\begin{aligned} & 0.35 \\ & 0.72 \end{aligned}$ |  | 0.3 0.6 | 1.0 |  | $\begin{aligned} & 0.24 \\ & 0.48 \end{aligned}$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $I_{D} \mathrm{P}$ | Output Drive Current P-Channel (4001) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=2.5 \mathrm{~V}, V_{1}=V_{S S} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}, V_{1}=V_{S S} \end{aligned}$ | $\left\lvert\, \begin{gathered} -0.35 \\ -0.3 \end{gathered}\right.$ |  | $\begin{gathered} -0.3 \\ -0.25 \end{gathered}$ | $\begin{aligned} & -2.0 \\ & -1.0 \end{aligned}$ |  | $\begin{aligned} & -0.24 \\ & -0.2 \end{aligned}$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $I_{D} \mathrm{~N}$ | Output Drive Current N-Channel (4011) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}, V_{1}=V_{D D} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}, V_{1}=V_{D D} \end{aligned}$ | $\begin{gathered} 0.145 \\ 0.3 \end{gathered}$ |  | $\begin{aligned} & 0.12 \\ & 0.25 \end{aligned}$ | $\begin{aligned} & 0.5 \\ & 0.6 \end{aligned}$ |  | $\begin{gathered} 0.095 \\ 0.2 \end{gathered}$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $I_{D} P$ | Output Drive Current P-Channel (4011) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=2.5 \mathrm{~V}, V_{1}=V_{S S} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}, V_{1}=V_{S S} \end{aligned}$ | $\left\|\begin{array}{l} -0.145 \\ -0.35 \end{array}\right\|$ |  | $\left\lvert\, \begin{aligned} & -0.12 \\ & -0.3 \end{aligned}\right.$ | -0.5 -1.2 |  | $\left\|\begin{array}{c} -0.095 \\ -0.24 \end{array}\right\|$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| 1 | Input Current |  |  |  |  | 10 |  |  |  | pA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$. Typical temperature coefficient for all values of $\mathrm{V}_{D D}=0.3 \% /{ }^{\circ} \mathrm{C}$

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CD4001M |  |  |  |  |  |  |
| $\mathrm{t}_{\text {PHL }}$ | Propagation Delay Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 35 \\ & 25 \end{aligned}$ | $\begin{aligned} & 50 \\ & 40 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {PLH }}$ | Propagation Delay Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 35 \\ & 25 \end{aligned}$ | $\begin{aligned} & 65 \\ & 40 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {THL }}$ | Transition Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 65 \\ & 35 \end{aligned}$ | $\begin{aligned} & 125 \\ & 70 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {TLH }}$ | Transition Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 65 \\ & 35 \end{aligned}$ | $\begin{aligned} & 175 \\ & 75 \end{aligned}$ |  |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Any Input |  | 5.0 |  | pF |
| CD4001C |  |  |  |  |  |  |
| $\mathrm{t}_{\text {PHL }}$ | Propagation Delay Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | 35 25 | $\begin{aligned} & 80 \\ & 55 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {PLH }}$ | Propagation Delay Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 35 \\ & 25 \end{aligned}$ | $\begin{aligned} & 120 \\ & 65 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {THL }}$ | Transition Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 65 \\ & 35 \end{aligned}$ | $\begin{aligned} & 200 \\ & 115 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
|  | Transition Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 65 \\ & 35 \end{aligned}$ | $\begin{aligned} & 300 \\ & 125 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Any Input |  | 5.0 |  | pF |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$. Typical temperature coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CD4011M |  |  |  |  |  |  |
| $\mathrm{t}_{\text {PHL }}$ | Propagation Delay Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{aligned} & 75 \\ & 40 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {PLH }}$ | Propagation Delay Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{aligned} & 75 \\ & 40 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{t}_{\text {THL }}$ | Transition Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 75 \\ & 50 \end{aligned}$ | $\begin{aligned} & 125 \\ & 75 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| ${ }_{\text {t }}^{\text {TLH }}$ | Transition Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 75 \\ & 40 \end{aligned}$ | $\begin{aligned} & 100 \\ & 60 \end{aligned}$ | ns |
| $\mathrm{ClN}_{\text {IN }}$ | Input Capacitance | - Any Input |  | 5.0 |  | pF |
| CD4011C |  |  |  |  |  |  |
| $\mathrm{t}_{\text {PHL }}$ | Propagation Delay Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{aligned} & 100 \\ & 50 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{t}_{\text {PLH }}$ | Propagation Delay Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{aligned} & 100 \\ & 50 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| ${ }^{\text {thL }}$ | Transition Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 75 \\ & 50 \end{aligned}$ | $\begin{aligned} & 150 \\ & 100 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| ${ }^{\text {t }}$ LH | Transition Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 75 \\ & 40 \end{aligned}$ | $\begin{aligned} & 125 \\ & 75 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Any Input |  | 5.0 |  | pF |

## CD4001BM/CD4001BC Quad 2-Input NOR Buffered B Series Gate CD4011BM/CD4011BC Quad 2-Input NAND Buffered B Series Gate

## General Description

These quad gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N - and P . channel enhancement mode transistors. They have equal source and sink current capabilities and conform to standard B series output drive. The devices also have buffered outputs which improve transfer characteristics by providing very high gain.
All inputs are protected against static discharge with diodes to $V_{D D}$ and $V_{S S}$.

## Features

- Low power TTL compatibility
fan out of 2 driving 74L
Oil 1 driving 74LS
- $5 \mathrm{~V}-10 \mathrm{~V}-15 \mathrm{~V}$ parametric ratings
- Symmetrical output characteristics
- Maximum input leakage $1 \mu \mathrm{~A}$ at 15 V over full temperature range


## Schematic and Connection Diagrams


$1 / 4$ of device shown
$J=\overline{A+B}$
Logical " 1 " = High
Logical " 0 " = Low
*All inputs protected by standard CMOS protection circuit.


1/4 of device shown
$J=\overline{A \cdot B}$
Logical " 1 " = High
Logical " 0 " = Low
*All inputs protected by standard CMOS protection circuit.

CD4001BC/CD4001BM Dual-In-Line and Flat Package


CD4011BC/CD40118M
Dua!-!c-Li:2 and Flat Package


Tor view

## Absolute Maximum Ratings (Notes 1 and 2 ) Operating Conditions

Voltage at Any Pin
Package Dissipation
$V_{D D}$ Range
Storage Temperature
Lead Temperature (Soldering, 10 seconds)

$$
\begin{array}{r}
-0.5 \mathrm{~V} \text { to } \mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V} \\
500 \mathrm{~mW} \\
-0.5 \mathrm{VDC} \text { to }+18 \mathrm{VDC} \\
-65^{\circ} \mathrm{C} \text { to }+150^{\circ} \mathrm{C} \\
300^{\circ} \mathrm{C}
\end{array}
$$

Operating $V_{D D}$ Range
Operating Temperature Range CD4001BM, CD4011BM CD4001BC, CD4011BC
$3 V_{D C}$ to $15 V_{D C}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## DC Electrical Characteristics CD4001BM, CD4011BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | +25 ${ }^{\circ} \mathrm{C}$ |  |  | $+125^{\prime \prime} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| 'DD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.25 |  | 0.004 | 0.25 |  | 7.5 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.50 |  | 0.005 | 0.50 |  | 15 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 1.0 |  | 0.006 | 1.0 |  | 30 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  | $\left.V_{D D}=10 \mathrm{~V}\right\} \\|^{\circ} \mathrm{l}<1 \mu \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | $v$ |
|  |  | $\left.V_{D D}=10 \mathrm{~V}\right\}\left\|{ }^{1} \mathrm{O}\right\|<1 \mu \mathrm{~A}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 | . | 14.95 | 15 |  | 14.95 |  | $v$ |
| $V_{\text {IL }}$ | Low Leve! Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=4.5 \mathrm{~V}$ |  | 1.5 |  | 2 | 1.5 |  | 1.5 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.0 \mathrm{~V}$ |  | 3.0 |  | 4 | 3.0 |  | 3.0 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ |  | 4.0 |  | 6 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{\text {IH }}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ | 3.5 |  | 3.5 | 3 |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ | 7.0 |  | 7.0 | 6 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 11.0 |  | 11.0 | 9 |  | 11.0 |  | $\checkmark$ |
| IOL | Low Level Output Current | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{0}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | $m A$ |
| N | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.10 |  | $-10^{-5}$ | -0.10 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V}$ |  | 0.10 |  | $10^{-5}$ | 0.10 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: All voltages measured with respect to $\mathrm{V}_{\mathrm{SS}}$ unless otherwise specified.

DC Electrical Characteristics CD4001BC, CD4011BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+85^{\circ} \mathrm{C}$ |  | UNIT, |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 1 |  | 0.004 | 1 |  | 7.5 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 2 |  | 0.005 | 2 |  | 15 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 4 |  | 0.006 | 4 |  | 30 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ ) |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  | $\left.V_{D D}=10 \mathrm{~V}\right\}\left\|{ }^{\prime} \mathrm{O}\right\|<1 \mu \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$, $110 \mathrm{O}<1<1 \mathrm{~A}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | $v$ |
| VIL | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=4.5 \mathrm{~V}$ |  | 1.5 |  | 2 | 1.5 |  | 1.5 | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.0 \mathrm{~V}$ |  | 3.0 |  | 4 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=13.5 \mathrm{~V}$ |  | 4.0 |  | 6 | 4.0 |  | 4.0 | v |
| $\mathrm{V}_{\text {IH }}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.5 \mathrm{~V}$ | 3.5 |  | 3.5 | 3 |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ | 7.0 |  | 7.0 | 6 |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 11.0 |  | 11.0 | 9 |  | 11.0 |  | v |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| $\mathrm{I}^{\mathrm{OH}}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 | $\because$ | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ |  |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.30 |  | $-10^{-5}$ | -0.30 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.30 |  | $10^{-5}$ | 0.30 |  | 1.0 | $\mu \mathrm{A}$ |

## AC Electrical Characteristics CD4001BC, CD4001BM

$T_{A}=25^{\circ} \mathrm{C}$, Input $\mathrm{t}_{\mathrm{r}} ; \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns} . \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}$. Typical temperature coefficient is $0.3 \% /{ }^{\circ} \mathrm{C}$.

|  | PARAMETER | CONDITIONS | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL | Propagation Delay Time, High-to-Low Level | $V_{D D}=5 \mathrm{~V}$ | 120 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 35 | 70 | ns |
| tPLH | Propagation Delay Time, Low-to-High Level | $V_{D D}^{\prime \prime}=5 \mathrm{~V}$ | 110 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 35 | 70 | ns |
| tTHL, tTLH | Transition Time | $V_{D D}=5 \mathrm{~V}$ | 90 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 50 | 100 | ns |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ | 40 | 80 | ns |
| $\mathrm{CIN}_{\text {IN }}$ | Average Input Capacitance | Any Input | 5 | 7.5 | pF |
| CPD | Power Dissipation Capacity | Any Gate | 14 |  | pF |

## AC Electrical Characteristics CD4011BC, CD4011BM

$T_{A}=25^{\circ} \mathrm{C}$, Input $t_{r} ; t_{f}=20 \mathrm{~ns} . C_{L}=50 \mathrm{pF}, R_{L}=200 \mathrm{k}$. Typical Temperature Coefficient is $0.3 \% /{ }^{\circ} \mathrm{C}$.

| PARAMETER | CONDITIONS | TYP | MAX | UNITS |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL | Propagation Delay, High-to-Low Level | $V_{D D}=5 \mathrm{~V}$ | 120 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 35 | 70 | ns |
| tPLH | Propagation Delay, Low-to-High Level | $V_{D D}=5 \mathrm{~V}$ | 85 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 40 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 30 | 70 | ns |
| tTHL, tTLH | Transition Time | $V_{D D}=5 \mathrm{~V}$ | 90 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 40 | 80 | ns |
| CIN | Any Input | 5 | 7.5 | pF |  |
| CPD | Average Input Capacitance | Power Dissipation Capacity |  | 14 |  |

## Typical Performance Characteristics



FIGURE 1. Typical Transfer Characteristics


FIGURE 4. Typical Transfet Characteristics


FIGURE 2. Typical Transfer Characteristics


FIGURE 3. Typical Transfer Characteristics


FIGURE 6

Typical Performance Characteristics (Cont'd.)

FIGURE 7

FIGURE 8

FIGURE 9


FIGURE 11


FIGURE 13


FIGURE 14

| N National |  |  |
| :---: | :---: | :---: |
| CD4002M/CD4002C Dual 4-Input NOR Gate CD4012M/CD4012C Dual 4-Input NAND Gate |  |  |
| General Description | Features |  |
| These Mor and NaND gates are monoliticic complemen. | - Wide supply volase range | 3.0 V 1015 V |
|  | 0 Hio | ${ }^{1000}$ |
|  | Applications |  |
|  |  |  |
|  |  |  |
|  |  |  |

Connection Diagrams


CD4012


## Absolute Maximum Ratings (Note 1)

Voltage an Any Pin
$V_{S S}-0.3 V$ to $V_{D D}+0.3 V$ Operating Temperature Range CD4002M, CD4012M CD4002C, CD4012C
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

Storage Temperature Range Package Dissipation Operating $\mathrm{V}_{\mathrm{DD}}$ Range Lead Temperature (Soldering, 10 seconds) $300^{\circ} \mathrm{C}$
$\mathrm{V}_{\mathrm{SS}}+3.0 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{SS}}+15 \mathrm{~V}$

## DC Electrical Characteristics

| Parameter |  | Conditions | Limits |  |  |  |  |  |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $-55^{\circ} \mathrm{C}$ | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| $\mathrm{I}_{\mathrm{L}}$ | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 0.05 \\ 0.1 \end{gathered}$ |  | $\begin{array}{\|l\|} \hline 0.001 \\ 0.001 \end{array}$ | $\begin{gathered} 0.05 \\ 0.1 \end{gathered}$ |  | $\begin{aligned} & 3.0 \\ & 6.0 \end{aligned}$ | $\mu \mathrm{A}$ $\mu \mathrm{A}$ |
| $\mathrm{P}_{\mathrm{D}}$ | Quiescent Device |  | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  | 0.25 |  | 0.005 | 0.25 |  | 15 | $\mu \mathrm{W}$ |
|  | Dissipation/Package | $V_{D D}=10 \mathrm{~V}$ |  | 1.0 |  | 0.01 | 1.0 |  | 60 | $\mu \mathrm{W}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Output Voltage Low | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{\mathrm{DD}}, l_{0}=0 \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | Level | $V_{D D}=10 \mathrm{~V}, V_{l}=V_{D D}, l_{0}=0 \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Voltage High | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{S S}, \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  | Level | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{S S}, \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
| $\mathrm{V}_{\text {NL }}$ | Noise Immunity | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=3.6 \mathrm{~V}, \mathrm{l}_{\mathrm{O}}=0 \mathrm{~A}$ | 1.5 |  | 1.5 | 2.25 |  | 1.4 |  | V |
|  | (All Inputs) | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=7.2 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A}$ | 3.0 |  | 3.0 | 4.5 |  | 2.9 |  | V |
| $\mathrm{V}_{\mathrm{NH}}$ | Noise Immunity | $\mathrm{V}_{\text {DD }}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.95 \mathrm{~V}, \mathrm{I}_{0}=0 \mathrm{~A}$ | 1.4 |  | 1.5 | 2.25 |  | 1.5 |  | V |
|  | (All Inputs) | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{0}=2.9 \mathrm{~V}, \mathrm{l}_{\mathrm{O}}=0 \mathrm{~A}$ | 2.9 |  | 3.0 | 4.5 |  | 3.0 |  | V |
| $I_{D} N$ | Output Drive Current | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{\mathrm{DD}}$ | 0.5 |  | 0.40 | 1.0 |  | 0.28 |  | mA |
|  | N -Channel (4002) | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}, V_{I}=V_{D D}$ | 1.1 |  | 0.9 | 2.5 |  | 0.65 |  | mA |
| $I_{D} P$ | Output Drive Current | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=2.5 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{S S}$ | -0.62 |  | -0.5 | -2.0 |  | -0.35 |  | mA |
|  | P-Channel (4002) | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{S S}$ | -0.62 |  | -0.5 | -1.0 |  | -0.35 |  | mA |
| $I_{D} N$ | Output Drive Current | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{\mathrm{DD}}$ | 0.31 |  | 0.25 | 0.5 |  | 0.175 |  | mA |
|  | N-Channel (4012) | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}, V_{1}=V_{D D}$ | 0.63 |  | 0.5 | 0.6 |  | 0.35 |  | mA |
| $I_{D} P$ | Output Drive Current | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=2.5 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{S S}$ | -0.31 |  | -0.25 | -0.5 |  | -0.175 |  | mA |
|  | P-Channel (4012) | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{S S}$ | -0.75 |  | -0.6 | -1.2 |  | -0.4 |  | mA |
| 1 | Input Current |  |  |  |  | 10 |  |  |  | pA |

DC Electrical Characteristics - CD4002C, CD4012C

| Parameter |  | Conditions | Limits |  |  |  |  |  |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $-40^{\circ} \mathrm{C}$ | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IL | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.5 \\ & 5.0 \end{aligned}$ |  | $\begin{array}{\|l\|} \hline 0.005 \\ 0.005 \end{array}$ | $\begin{aligned} & 0.5 \\ & 5.0 \end{aligned}$ |  | $\begin{aligned} & 15 \\ & 30 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |
| $\mathrm{P}_{\mathrm{D}}$ | Quiescent Device Dissipation/Package |  | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 2.5 \\ & 50 \end{aligned}$ |  | $\begin{gathered} 0.025 \\ 0.05 \end{gathered}$ | $\begin{aligned} & 2.5 \\ & 50 \end{aligned}$ |  | $\begin{gathered} 75 \\ 300 \end{gathered}$ | $\begin{aligned} & \mu \mathrm{W} \\ & \mu \mathrm{~W} \end{aligned}$ |
| VoL | Output Voltage Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{1}=V_{D D}, l_{O}=0 \mathrm{~A} \\ & V_{D D}=10 \mathrm{~V}, V_{1}=V_{D D}, I_{O}=0 \mathrm{~A} \end{aligned}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ |  | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ | v |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Voltage High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{1}=V_{S S}, I_{O}=0 \mathrm{~A} \\ & V_{D D}=10 \mathrm{~V}, V_{1}=V_{S S}, l_{0}=0 \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ |  | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ | $\begin{aligned} & 5.0 \\ & 10 \end{aligned}$ |  | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ |  | $\begin{aligned} & \text { v } \\ & \text { v } \end{aligned}$ |
| $\mathrm{V}_{\mathrm{NL}}$ | Noise Immunity (All Inputs) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}} \geqslant 3.5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}} \geqslant 7.2 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ | $\begin{gathered} 2.25 \\ 4.5 \end{gathered}$ |  | $\begin{aligned} & 1.4 \\ & 2.9 \end{aligned}$ |  | v |
| $\mathrm{V}_{\mathrm{NH}}$ | Noise Immunity (All Inputs) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O} \leqslant 1.5 \mathrm{~V}, I_{0}=0 \mathrm{~A} \\ & V_{D D}=10 \mathrm{~V}, V_{O} \leqslant 3.5 \mathrm{~V}, I_{O}=0 \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 1.4 \\ & 2.9 \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ | $\begin{gathered} 2.25 \\ 4.5 \end{gathered}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ |  | $v$ |
| $I_{\text {d }} \mathrm{N}$ | Output Drive Current N -Channel (4002) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}, V_{1}=V_{D D} \\ & V_{D D}=10 \mathrm{~V}, V_{D}=0.5 \mathrm{~V}, V_{I}=V_{D D} \end{aligned}$ | $\begin{aligned} & 0.35 \\ & 0.72 \end{aligned}$ |  | $\begin{aligned} & 0.3 \\ & 0.6 \end{aligned}$ | $\begin{aligned} & 1.0 \\ & 2.5 \end{aligned}$ |  | $\begin{aligned} & 0.24 \\ & 0.48 \end{aligned}$ |  | $\begin{gathered} \mathrm{mA} \\ \mathrm{~mA} \end{gathered}$ |
| $I_{D} \mathrm{P}$ | Output Drive Current P-Channel (4002) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=2.5 \mathrm{~V}, V_{1}=V_{S S} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}, V_{I}=V_{S S} \end{aligned}$ | $\begin{array}{\|c} -0.35 \\ -0.3 \end{array}$ |  | $\begin{aligned} & -0.3 \\ & -0.25 \end{aligned}$ | $\begin{array}{\|l\|l\|} \hline-2.0 \\ -1.0 \end{array}$ |  | $\begin{array}{\|c} -0.24 \\ -0.2 \end{array}$ |  | $\begin{gathered} \mathrm{mA} \\ \mathrm{~mA} \end{gathered}$ |
| $I_{0} \mathrm{~N}$ | Output Drive Current N -Channel (4012) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}, V_{1}=V_{D D} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}, V_{1}=V_{D D} \end{aligned}$ | $\begin{array}{\|c\|} \hline 0.145 \\ 0.3 \\ \hline \end{array}$ |  | $\begin{aligned} & 0.12 \\ & 0.25 \end{aligned}$ | $\begin{aligned} & 0.5 \\ & 0.6 \end{aligned}$ |  | $\begin{gathered} 0.095 \\ 0.2 \end{gathered}$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $1_{0} P$ | Output Drive Current P-Channel (4012) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=2.5 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{\mathrm{SS}} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{\mathrm{SS}} \end{aligned}$ | $\left\|\begin{array}{l} -0.145 \\ -0.35 \end{array}\right\|$ |  | $\begin{aligned} & -0.12 \\ & -0.3 \end{aligned}$ | $\begin{array}{\|l\|} \hline-0.5 \\ -1.2 \end{array}$ |  | $\left\|\begin{array}{c} -0.095 \\ -0.24 \end{array}\right\|$ |  | $\begin{gathered} \mathrm{mA} \\ \mathrm{~mA} \end{gathered}$ |
| 1 | Input Current |  |  |  |  | 10 |  |  |  | pA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$.

| Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| CD4002M |  |  |  |  |  |
| $\mathrm{t}_{\text {PHL }}$ Propagation Delay Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 35 \\ & 25 \end{aligned}$ | $\begin{aligned} & 50 \\ & 40 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pLH }}$ Propagation Delay Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 V \\ & V_{D D}=10 V \end{aligned}$ |  | $\begin{aligned} & 35 \\ & 25 \end{aligned}$ | $\begin{aligned} & 50 \\ & 40 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {THL }}$ Transition Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 65 \\ & 35 \end{aligned}$ | $\begin{aligned} & 175 \\ & 75 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {TLH }}$ Transition Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 65 \\ & 35 \end{aligned}$ | $\begin{aligned} & 125 \\ & 70 \end{aligned}$ | ns ns |
| $\mathrm{C}_{\text {IN }}$ Input Capacitance | Any Input |  | 5.0 |  | pF |
| CD4002C |  |  |  |  |  |
| $t_{\text {PHL }}$ Propagation Delay Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 35 \\ & 25 \end{aligned}$ | $\begin{gathered} 120 \\ 65 \end{gathered}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {pLH }}$ Propagation Delay Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 35 \\ & 25 \end{aligned}$ | $\begin{aligned} & 80 \\ & 55 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{t}_{\text {THL }}$ Transition Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 65 \\ & 35 \end{aligned}$ | $\begin{aligned} & 300 \\ & 125 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {TLH }}$ Transition Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 V \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 65 \\ & 35 \end{aligned}$ | $\begin{aligned} & 200 \\ & 115 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ Input Capacitance | Any input |  | 5.0 |  | pF |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=20$ ns. Typical temperature coefficient for all values of $V_{D D}=0.3 \% /{ }^{\circ} \mathrm{C}$

| Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| CD4012M |  |  |  |  |  |
| $\mathrm{t}_{\text {PHL }}$ Propagation Delay Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{aligned} & 75 \\ & 40 \end{aligned}$ | ns ns |
| $t_{\text {pLH }}$ Propagation Delay Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{aligned} & 75 \\ & 40 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {THL }}$ Transition Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 V \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 75 \\ & 50 \end{aligned}$ | $\begin{aligned} & 125 \\ & 75 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {TLH }}$ Transition Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 75 \\ & 40 \end{aligned}$ | $\begin{gathered} 100 \\ 60 \end{gathered}$ | ns ns |
| $\mathrm{C}_{\mathrm{IN}} \quad$ Input Capacitance | Any Input |  | 5.0 |  | pF |
| CD4012C |  |  |  |  |  |
| $\mathrm{t}_{\text {PHL }}$ Propagation Delay Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{gathered} 100 \\ 50 \end{gathered}$ | ns ns |
| $\mathrm{t}_{\text {pLH }}$ Propagation Delay Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{gathered} 100 \\ 50 \end{gathered}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {THL }}$ Transition Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 75 \\ & 50 \end{aligned}$ | $\begin{aligned} & 150 \\ & 100 \end{aligned}$ | ns ns |
| $t_{\text {TLH }}$ Transition Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 75 \\ & 40 \end{aligned}$ | $\begin{aligned} & 125 \\ & 75 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ Input Capacitance | Any Input |  | 5.0 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

## CD4002BM/CD4002BC Dual 4-Input NOR Gate CD4012BM/CD4012BC Dual 4-Input NAND Gate

## General Description

These dual gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N -and P-channel enhancement mode transistors. They have equal source and sink current capabilities and conform to standard B series output drive. The devices also have buffered outputs which improve transfer characteristics by providing very high gain. All inputs are protected against static discharge with diodes to $V_{D D}$ and $V_{S S}$.

## Features

- Wide supply voltage range
3.0 V to 15 V
$0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
fanout of 2 driving 74L or 1 driving 74LS
- Low power TTL compatibility
- 5V-10V-15V parametric ratings
- Symmetrical output characteristics
- Maximum input leakage $1 \mu \mathrm{~A}$ at 15 V over full temperature range


## Connection Diagram

CD4002BM/CD4002BC


CD4012BM/CD4012BC


Absolute Maximum Ratings (Notes 1 and 2)
$V_{D D}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{s}}$ Storage Temperature Range
$P_{D}$ Package Dissipation
$T_{L}$ Lead Temperature (soldering, 10 seconds)
-0.5 V to +18 V
-0.5 to $V_{D D} 0.5 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW $300^{\circ} \mathrm{C}$

## Recommended Operating Conditions (Note 2)

$\mathrm{V}_{\mathrm{DD}}$ Supply Voltage
3.0 to 15 V
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range
CD4002BM, CD4012BM
CD4002BC, CD4012BC

0 V to $\mathrm{V}_{\mathrm{DD}} \mathrm{V}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

DC Electrical Characteristics (Note 2) - CD4002BM, CD4012BM

| Parameter |  | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| $\mathrm{I}_{\mathrm{DD}}$ | Quiescent |  | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  | 0.25 |  | 0.004 | 0.25 |  | 7.5 | $\mu \mathrm{A}$ |
|  | Device Current | $V_{D D}=10 \mathrm{~V}$ |  | 0.5 |  | 0.005 | 0.5 |  | 15 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 1.0 |  | 0.006 | 1.0 |  | 30 | $\mu \mathrm{A}$ |
| VoL | Low Level | $V_{\text {DD }}=5.0 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | Output Voltage | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level | $V_{\text {DD }}=5.0 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  | Output Voltage | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | v |
|  | Input Voltage | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | $v$ |
| $\mathrm{V}_{\mathrm{IH}}$ | High Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  | Input Voltage | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | $\checkmark$ |
| IoL | Low Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  | Output Current | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.2 |  | 0.90 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.0 |  | 2.4 |  | mA |
| $\mathrm{I}^{\mathrm{OH}}$ | High Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  | Output Current | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.2 |  | -0.90 |  | mA |
|  |  | $\mathrm{V}_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.0 |  | -2.4 |  | mA |
| NוN | Input Current | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} -0.10 \\ 0.10 \end{gathered}$ |  | $\begin{gathered} -10^{-5} \\ 10^{5} \end{gathered}$ | $\begin{gathered} -0.10 \\ 0.10 \end{gathered}$ |  | $\begin{gathered} -1.0 \\ 1.0 \end{gathered}$ | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $\mathrm{v}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

DC Electrical Characteristics (Note 2) - CD4002BC, CD4012BC


AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {PHL }}$ | Propagation Delay, High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 125 \\ & 60 \\ & 45 \end{aligned}$ | $\begin{aligned} & 250 \\ & 100 \\ & 70 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{t}_{\text {PLH }}$ | Propagation Delay, Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 125 \\ & 60 \\ & 45 \end{aligned}$ | $\begin{aligned} & 250 \\ & 100 \\ & 70 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| ${ }^{\text {THL }}$, $\mathrm{t}_{\text {TLH }}$ | Transition Time | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 50 \\ & 40 \end{aligned}$ | $\begin{gathered} 200 \\ 100 \\ 80 \end{gathered}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ | Average Input Capacitance (Note 3) | Any Input |  | 5.0 | 7.5 | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacity (Note 4) | Any Gate |  | 20 |  | pF |

Note 3: Capacitance is guaranteed by periodic testing.
Note 4: $\mathrm{C}_{P D}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics, Application Note AN-90.

## CD4006BM/CD4006BC 18-Stage Static Shift Register

## General Description

The CD4006BM/CD4006BC 18-stage static shift register is comprised of four separate shift register sections, two sections of four stages and two sections of five stages. Each section has an independent data input. Outputs are available at the fourth stage and the fifth stage of each section. A common clock signal is used for all stages. Data is shifted to the next stage on the negative-going transition of the clock. Through appropriate connections of inputs and outputs, multiple register sections of $4,5,8$, and 9 stages, or single register sections of $10,12,13,14,16,17$, and 18 stages can be implemented using one package.

## Features

$\begin{array}{lr}\text { - Wide supply voltage range } & 3.0 \mathrm{~V} \text { to } 15 \mathrm{~V} \\ \text { - High noise immunity } & 0.45 \mathrm{~V}_{\mathrm{DD}} \text { (typ.) }\end{array}$

- Low power TTL
fan out of 2 drving 74L
or 1 driving 74LS
- Low clock input capacitance

6 pF (typ.)

- Medium speed $\quad 10 \mathrm{MHz}$ (typ.) (with $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ )
- Low power
- Fully static operation


## Logic Diagrams



Connection Diagram
Truth Table


| $D$ | $C L^{\Delta}$ | $D+1$ |
| :---: | :---: | :---: |
| 0 | - | 0 |
| 1 | $\square$ | 1 |
| $X$ | - | $N C$ |

X = Don't care
$\Delta=$ Level change
$N C=$ No change

## Absolute Maximum Ratings

(Notes 1 and 2)
$V_{D D}$ DC Supply Voltage
-0.5 to $+18 V_{D C}$
$V_{\text {IN }}$ Input Voltage -0.5 to $V_{D D}+0.5 V_{D C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
$T_{S}$ Storage Temperature Range
PD Package Dissipation
$\mathrm{T}_{\mathrm{L}}$ Lead Temperature (Soldering, 10 seconds) $300^{\circ} \mathrm{C}$

Recommended Operating Conditions
(Note 2)
$V_{D D}$ DC Supply Voltage
+3.0 to +15 V
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range
CD4006BM
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

DC Electrical Characteristics CD4006BM (Note 2)

| Parameter |  | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IDD | Quiescent |  | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  | 5.0 |  | 0.005 | 5.0 |  | 150 | $\mu \mathrm{A}$ |
|  | Device Current | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  | 0.010 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  | 0.015 | 20 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level | $V_{D D}=5.0 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | Output Voltage | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  | Output Voltage | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  | Input Voltage | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $V_{1 H}$ | High Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  | Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| $\mathrm{I}_{\text {OL }}$ | Low Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  | Output Current | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| $\mathrm{I}_{\mathrm{OH}}$ | High Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  | Output Current | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| In | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -0.1 |  | -0.1 | $-10^{-5}$ |  | -1.0 |  | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

## DC Electrical Characteristics CD4006BC (Note 2)

| Parameter |  | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IDD | Quiescent |  | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  | 20 |  | 0.005 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  | Device Current | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.010 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 0.015 | 80 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level | $V_{D D}=5.0 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $\checkmark$ |
|  | Output Voltage | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level | $V_{D D}=5.0 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  | Output Voltage | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  | Input Voltage | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{1 \mathrm{H}}$ | High Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  | Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V | 11 |  | 11 | 8.25 |  | 11 |  | V |

DC Electrical Characteristics (cont'd) CD4006BC (Note 2)

| Parameter |  | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IOL | Low Level Output Current |  | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| $\mathrm{I}_{\mathrm{OH}}$ | High Level Output Current | $\begin{aligned} & V_{I L}=0 \mathrm{~V}, V_{I H}=V_{D D} \\ & V_{D D}=5.0 \mathrm{~V}, V_{O}=4.6 \mathrm{~V} \end{aligned}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | -0.3 | -8.8 | -8.8 | -2.4 |  | mA |
| In | Input Current | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V} \end{aligned}$ | -0.3 | 0.3 | -0.3 | $\begin{gathered} -10^{-5} \\ 10^{-5} \end{gathered}$ | 0.3 | -1.0 | 1.0 | $\mu \mathrm{A}$ $\mu \mathrm{A}$ |

AC Electrical Characteristics CD4006BM/CD4006BC $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted

| Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{PLH}}, \mathrm{t}_{\text {PHL }}$ Propagation Delay Time ( $\left.\mathrm{t}_{\text {PLH }}=\mathrm{t}_{\text {PHL }}\right)$ | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} \hline 200 \\ 100 \\ 80 \end{gathered}$ | $\begin{aligned} & 400 \\ & 200 \\ & 150 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {TLH }}, \mathrm{t}_{\text {THL }}$ Transition Time ( $\mathrm{t}_{\text {TLH }}=\mathrm{t}_{\text {THL }}$ ) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 50 \\ & 40 \end{aligned}$ | $\begin{gathered} 200 \\ 100 \\ 80 \end{gathered}$ | ns <br> ns <br> ns |
| $t_{\text {WL }}, t_{\text {WH }}$ Minimum Clock Pulse Width ( $t_{\text {WL }}=t_{\text {WH }}$ ) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 45 \\ & 35 \end{aligned}$ | $\begin{gathered} 200 \\ 100 \\ 70 \end{gathered}$ | ns <br> ns <br> ns |
| $\mathrm{t}_{\mathrm{RCL}}, \mathrm{t}_{\mathrm{FCLL}}$ Clock Rise and Fall Time ( $\mathrm{t}_{\mathrm{RCL}}=\mathrm{t}_{\mathrm{FCL}}$ ) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 15 \\ & 15 \\ & 15 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \\ & \mu \mathrm{~S} \end{aligned}$ |
| $\mathrm{t}_{\text {SU }} \quad$ Minimum Set-up Time | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \\ & 20 \end{aligned}$ | $\begin{gathered} 100 \\ 50 \\ 40 \end{gathered}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{H} \quad$ Minimum Hold Time | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 55 \\ & 35 \\ & 30 \end{aligned}$ | $\begin{gathered} 110 \\ 70 \\ 60 \end{gathered}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{f}_{\mathrm{CL}} \quad$ Maximum Clock Frequency | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 2.5 \\ & 5.0 \\ & 7.0 \end{aligned}$ | $\begin{aligned} & 5.0 \\ & 12 \\ & 16 \end{aligned}$ |  | MHz MHz MHz |
| $\mathrm{C}_{\mathrm{L}} \quad$ Input Capacitance | Data Input CLK Input |  | $\begin{aligned} & 5.0 \\ & 7.5 \end{aligned}$ |  | $\begin{aligned} & \mathrm{pF} \\ & \mathrm{pF} \end{aligned}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

## Switching Time Waveforms



## CD4007M/CD4007C Dual Complementary Pair Plus Inverter

## General Description

The CD4007M/CD4007C consists of three complementary pairs of N - and P -channel enhancement mode MOS transistors suitable for series/shunt applications. All inputs are protected from static discharge by diode clamps to $V_{D D}$ and $V_{S S}$.

For proper operation the voltages at all pins must be constrained to be between $V_{S S}-0.3 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{DD}}+0.3 \mathrm{~V}$ at all times.

Features

- Wide supply voltage range 3.0 V to 15 V
- High noise immunity
$0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.)


## Connection Diagram



Note: All P-channel substrates are connected to VDD and all N -channel substrates are connected to $\mathrm{V}_{\mathbf{S S}}$.

Voltage at Any Pin Operating Temperature Range CD4007M CD4007C
$V_{S S}-0.3 V$ to $V_{D D}+0.3 V$

$$
\begin{gathered}
-55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \\
-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C}
\end{gathered}
$$

Storage Tempeature Range Package Dissipation Operating $V_{D D}$ Range Lead Temperature (Soldering, 10 seconds)
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$\mathrm{V}_{\mathrm{SS}}+3.0 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{SS}}+15 \mathrm{~V}$
$300^{\circ} \mathrm{C}$

## DC Electrical Characteristics - CD4007M

| Parameter |  | Conditions | Limits |  |  |  |  |  |  |  |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $-55^{\circ} \mathrm{C}$ | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |
|  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |
| $L_{L}$ | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{array}{\|c\|} \hline 0.05 \\ 0.1 \end{array}$ |  | $\begin{aligned} & 0.001 \\ & 0.001 \end{aligned}$ | $\begin{gathered} 0.05 \\ 0.1 \end{gathered}$ |  |  | $\begin{aligned} & 3.0 \\ & 6.0 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |
| $\mathrm{P}_{\mathrm{D}}$ | Quiescent Device Dissipation/Package |  | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{gathered} 0.25 \\ 1.0 \end{gathered}$ |  | $\begin{aligned} & 0.005 \\ & 0.001 \end{aligned}$ | $\begin{array}{c\|c} 0.25 \\ 1.0 \end{array}$ |  |  | $\begin{aligned} & 15 \\ & 60 \end{aligned}$ | $\begin{aligned} & w \\ & W W \end{aligned}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Output Voltage Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ |  | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ |  |  | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Voltage High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ |  |  | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ | $\begin{aligned} & 5.0 \\ & 10 \end{aligned}$ |  | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ |  |  | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\mathrm{NL}}$ | Noise Immunity (All inputs) | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=3.6 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=7.2 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ | $\begin{gathered} 2.25 \\ 4.5 \end{gathered}$ |  | $\begin{aligned} & 1.4 \\ & 2.9 \end{aligned}$ |  |  | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\mathrm{NH}}$ | Noise Immunity (All inputs) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.95 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=2.9 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 1.4 \\ & 2.9 \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ | $\begin{gathered} 2.25 \\ 4.5 \end{gathered}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ |  |  | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $I_{0} \mathrm{~N}$ | Output Drive Current N -Channel | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}, V_{1}=V_{D D} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}, V_{1}=V_{D D} \end{aligned}$ | $\begin{gathered} 0.75 \\ 1.6 \end{gathered}$ |  |  | $\begin{aligned} & 0.6 \\ & 1.3 \end{aligned}$ | $\begin{aligned} & 1.0 \\ & 2.5 \end{aligned}$ |  | $\begin{gathered} 0.4 \\ 0.95 \end{gathered}$ |  |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $I_{D} P$ | Output Drive Current P-Channel | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=2.5 \mathrm{~V}, V_{1}=V_{S S} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}, V_{1}=V_{S S} \end{aligned}$ | $\left\|\begin{array}{l} -1.75 \\ -1.35 \end{array}\right\|$ |  |  | $\left\lvert\, \begin{aligned} & -1.4 \\ & -1.1 \end{aligned}\right.$ | $\begin{array}{\|l} -4.0 \\ -2.5 \end{array}$ |  | -1.0 -0.75 |  |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| 1 | Input Current |  |  |  |  |  | 10 |  |  |  |  | pA |

## DC Electrical Characteristics - CD4007C

|  | Parameter | Conditions | Limits |  |  |  |  |  |  |  |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |
| $\mathrm{I}_{\mathrm{L}}$ | Quiescent Device Current | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ |  | $\begin{array}{l\|} 0.005 \\ 0.005 \end{array}$ | $\begin{aligned} & 0.5 \\ & 1.0 \end{aligned}$ |  |  | $\begin{aligned} & 15 \\ & 30 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |
| $P_{\text {D }}$ | Quiescent Device Dissipation/Package | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 2.5 \\ & 10 \end{aligned}$ |  | $\left.\begin{gathered} 0.025 \\ 0.05 \end{gathered} \right\rvert\,$ | $\begin{aligned} & 2.5 \\ & 10 \end{aligned}$ |  |  | $\begin{array}{r} 75 \\ 300 \end{array}$ | $\mu \mathrm{W}$ $\mu \mathrm{W}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Output Voltage Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ |  | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & 0.01 \\ & 0.01 \end{aligned}$ |  |  | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \mathrm{V} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Voltage High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ |  |  | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ | $\begin{gathered} 5.0 \\ 10 \end{gathered}$ |  | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{NL}}$ | Noise Immunity (All inputs) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=3.6 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=7.2 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ | $\begin{array}{\|c\|c} 2.25 \\ 4.5 \end{array}$ |  | $\begin{aligned} & 1.4 \\ & 2.9 \end{aligned}$ |  |  | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{V}_{\mathrm{NH}}$ | Noise Immunity (All inputs) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.95 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=2.9 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 1.4 \\ & 2.9 \end{aligned}$ |  |  | 1.5 3.0 | $\begin{gathered} 2.25 \\ 4.5 \end{gathered}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ |  |  | V |
| $\mathrm{I}_{\mathrm{D}} \mathrm{N}$ | Output Drive Current N-Channel | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}, V_{1}=V_{D D} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}, V_{1}=V_{D D} \end{aligned}$ | $\begin{gathered} 0.35 \\ 1.2 \end{gathered}$ |  |  | $\begin{aligned} & 0.3 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & 1.0 \\ & 2.5 \end{aligned}$ |  | $\begin{gathered} 0.24 \\ 0.8 \end{gathered}$ |  |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $I_{D} P$ | Output Drive Current P-Channel | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=2.5 \mathrm{~V}, V_{1}=V_{S S} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}, V_{1}=V_{S S} \end{aligned}$ | $\begin{array}{\|l\|} -1.3 \\ -0.65 \end{array}$ |  |  | $\left\|\begin{array}{l} -1.1 \\ -0.55 \end{array}\right\|$ | $\begin{array}{\|l\|} \hline-4.0 \\ -2.5 \end{array}$ |  | $\begin{aligned} & -0.9 \\ & -0.45 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| 1 | Input Current |  |  |  |  |  | 10 |  |  |  |  | pA |

[^18]AC Electrical Characteristics - CD4007M $T_{A}=25^{\circ} \mathrm{C}$ and $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ and rise and fall times $=20 \mathrm{~ns}$. Typical temperature coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$

| Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {PLH }}=t_{\text {PHL }}$ Propagation Delay Time | $V_{D D}=5.0 \mathrm{~V}$ |  | 35 | 60 | ns |
|  | $\mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}$ |  | 20 | 40 | ns |
| $\mathrm{t}_{\mathrm{TLH}}=\mathrm{t}_{\mathrm{THL}}$ Transition Time | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  | 50 | 75 | ns |
| $\mathrm{C}_{1}$ | $\mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}$ |  | 30 | 40 | ns |
|  | Any Input |  | 5.0 |  | pF |

AC Electrical Characteristics CD4007C $T_{A}=25^{\circ} \mathrm{C}$ and $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ and rise and fall times $=20 \mathrm{~ns}$. Typical temperature coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$

| Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{PLH}}=\mathrm{t}_{\text {PHL }}$ Propagation Delay Time | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  | 35 | 75 | ns |
|  | $\mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}$ |  | 20 | 50 | ns |
| $\mathrm{t}_{\mathrm{TLH}}=\mathrm{t}_{\mathrm{THL}}$ Transition Time | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  | 50 | 100 | ns |
|  | $\mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}$ |  | 30 | 50 | ns |
| $\mathrm{C}_{1} \quad$ Input Capacitance | Any Input |  | 5 |  | pF |

## AC Test Circuits



## Switching Time Waveforms



## CD4008BM/CD4008BC 4-Bit Full Adder

## General Description

The CD4008B types consist of four full-adder stages with fast look-ahead carry provision from stage to stage. Circuitry is included to provide a fast "parallel-carry-out" bit to permit high-speed operation in arithmetic sections using several CD4008B's. CD4008B inputs include the four sets of bits to be added, A1 to A4 and B1 to B4, in addition to the "Carry in" bit from a previous section. CD4008B outputs include the four sum bits, S1 and S4, in addition to the high-speed "parallel-carry-out" which may be utilized at a succeeding CD4008B section.
All inputs are protected from damage due to static discharge by diode clamps to $V_{D D}$ and GND.

## Features

- Wide supply voltage range 3.0 V to 15 V

■ High noise immunity $0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.)

- Low power TTL compatibility
fan out of 2 driving 74L
or 1 driving 74LS
- 4 sum outputs plus parallel look-ahead carry-output
- Quiescent current specified to $15-\mathrm{V}$
- Maximum input leakage of $1 \mu \mathrm{~A}$ at 15 V (full package temperature range)


## Block Diagram



## Connection Diagram

Dual-In-Line and Flat Package


TOP VIEW

Truth Table

| $\mathrm{A}_{\mathbf{i}}$ | $\mathrm{B}_{\mathbf{i}}$ | $\mathrm{C}_{\mathbf{i}}$ | CO | SUM |
| :---: | :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | 0 | 0 |
| 1 | 0 | 0 | 0 | 1 |
| 0 | 1 | 0 | 0 | 1 |
| 1 | 1 | 0 | 1 | 0 |
| 0 | 0 | 1 | 0 | 1 |
| 1 | 0 | 1 | 1 | 0 |
| 0 | 1 | 1 | 1 | 0 |
| 1 | 1 | 1 | 1 | 1 |

Absolute Maximum Ratings
(Notes 1 and 2)
VDD dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{S}}$ Storage Temperature Range
PD Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
-0.5 to $+18 V_{D C}$
-0.5 to $V_{D D}+0.5 V_{D C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW $300^{\circ} \mathrm{C}$

Recommended Operating Conditions
(Note 2)
$\begin{array}{lr}V_{D D} \text { dc Supply Voltage } & 3 \text { to } 15 V_{D C} \\ V_{\text {IN Input Voltage }} & 0 \text { to } V_{D D} V_{D C} \\ T_{A} \text { Operating Temperature Range } & -55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \\ \text { CD4008BM } & -40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C}\end{array}$
DC Electrical Characteristics 4008BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 5 |  | 0.3 | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  | 0.5 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  | 1.0 | 20. |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $\\|_{0} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $\\|_{0} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| $V_{\text {IL }}$ | Low Level Input Voltage | $\left\|\\|_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V |  | 1.5 3.0 |  |  | 1.5 3.0 |  | 1.5 3.0 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | v |
| $V_{I H}$ | High Level Input Voltage | $\\| \mathrm{l}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 |  |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | v |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| ${ }^{10 H}$ | High Level Output Current | $V_{\text {DD }}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.25 |  | -0.2 | -0.35 |  | -0.14 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -0.62 |  | -0.5 | -0.8 |  | -0.35 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -1.8 |  | -1.5 | -3.5 |  | -1.1 |  | mA |
| In | Input Current | $V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

DC Electrical Characteristics 4008BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| ${ }^{1} \mathrm{DD}$ | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 20 |  | 0.5 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  |  |  | 40 |  | 1 | 40 |  | 300 | - $\mu \mathrm{A}$ |
|  |  |  |  | 80 |  | 5 | 80 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $\begin{aligned} & \left\|I_{O}\right\|<1 \mu \mathrm{~A} \\ & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  |  |  |  |  |  |  |  |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\\| \mathrm{ll}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 V$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| VIL | Low Level Input Voltage | $\mid \mathrm{I}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$, |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  |  | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | V |
| $V_{\text {IH }}$ | High Level Input Voltage | $\\|_{0} \mathrm{l}<1 \mu \mathrm{~A}$, |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1 \mathrm{~V} \text { or } 9 \mathrm{~V}$ | $7.0$ |  | 7.0 |  |  | 7.0 | . | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | V |


| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IOL | Low Level Output Current |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| ${ }^{\mathrm{O}} \mathrm{H}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V} ; \quad V_{0}=4.6 \mathrm{~V}$ | -0.2 |  | -0.16 | -0.35 |  | -0.12 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -0.5 |  | -0.4 | -0.8 |  | -0.3 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -1.4 | - | -1.2 | -3.5 |  | $-1.0$ |  | mA |
| In | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  |  | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$, |  | 0.3 |  |  | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $\mathrm{T}_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{PF}, \mathrm{R}_{\mathrm{L}}=2000 \mathrm{k}$, input $\mathrm{t}_{\mathrm{t}}, \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified.


Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=\mathrm{OV}$ unless otherwise specified.
Note 3: CPD determines the no load ac power consumption of any CMOS device. For complete explanation, see 54C/74C Family Characteristics application note, AN-90.

## AC Test Circuit and Switching Time Waveforms



## CD4009M/CD4009C Hex Buffers (Inverting) CD4010M/CD4010C Hex Buffers (Non-Inverting)

## General Description

These hex buffers are monolithic complementary MOS (CMOS) integrated circuits. The N - and P-channel enhancement mode transistors provide a symmetrical circuit with output swings essentially equal to the supply voltage. This results in high noise immunity over a wide supply voltage range. No DC power other than that caused by leakage current is consumed during static conditions. All inputs are protected against static discharge. These gates may be used as hex buffers, CMOS to DTL or TTL interface or as CMOS current drivers. Conversion ranges are from 3 to 15 volts providing $V_{C C} \leqslant V_{D D}$.

## Features

| Wide supply voltage range | 3.0 V to 15 V |
| :--- | ---: |
| Low power | 100 nW (typ.) |
| High noise immunity | $0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.) |
| $\left.\begin{array}{lr}\text { High current sinking } & 8 \mathrm{~mA} \text { (min.) at } \mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V} \\ \text { capability } & \text { and } \mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}\end{array}\right)$ |  |

Applications

| $\pm$ Automotive | ¢ Alarm system |
| :---: | :---: |
| - Data terminals | ( Industrial controls |
| Instrumentation | a Remote metering |
| Medical electron | * Computers |

## Connection Diagrams


top view



Note 1: This device should not be connected to circuits with the power on because high transient voltage may cause permanent damage.
AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, unless otherwise noted
Typical Temperature Coefficient for all values of $V_{D D}=0.3 \% /{ }^{\circ} \mathrm{C}$

| CHARACTERISTIC | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CD40XXM |  |  | CD40xxC |  |  |  |
|  |  | $\begin{gathered} V_{\text {DD }} \\ \text { (VOLTS) } \end{gathered}$ | MIN | TYP | MAX | MIN | TYP | MAX |  |
| Propagation Delay Time High to Low Level (tpHL) | $V_{\text {cc }}=V_{\text {OD }}$ | 5 | - | 15 | 55 | - | 15 | 70 | ns |
|  |  | 10 | - | 10 | 30 | - | 10 | 40 |  |
|  | $V_{D D}=10 \mathrm{~V}$ |  | - | 10 | 25 | - | 10 | 35 |  |
|  | $\mathrm{V}_{\mathrm{cc}}=5 \mathrm{~V}$ |  | - | - | 25 | - | 10 | 35 |  |
| Low to. High Level (tpLH) |  | 5 | - | 50 | 80 | - | 50 | 100 | ns |
|  | $V_{C C}=V_{\text {DD }}$ | 10 | - | 25 | 55 | - | 25 | 70 |  |
|  | $V_{D D}=10 \mathrm{~V}$ |  | - | 15 | 30 | - | 15 | 40 |  |
|  | $\mathrm{V}_{\mathrm{cc}}=5 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
| Transition Time: <br> High to Low Level (tinl) | $V_{C C}=V_{D D}$ | 5 | - | 20 | 45 | -. | 20 | 60 | ns |
|  |  | 10 | - | 16 | 40 | - |  | 50 |  |
|  |  | 5 | - | 80 | 125 | - | 80 | 160 |  |
| Low.to-High Level (ttim) | $V_{C C}=V_{D O}$ | 10 | - | 50 | 100 | - | 50 | 120 | ns |
| Input Capacitance ( $\mathrm{C}_{1}$ ) | Any Inout |  | - | 5 | - | - | 5 | - | pF |

Typical Applications


## CD4013BM/CD4013BC Dual D Flip.Flop

## General Description

The CD4013B dual D flip-flop is a monolithic complementary MOS (CMOS) integrated circuit constructed with N - and P -channel enhancement mode transistors. Each flip-flop has independent data, set, reset, and clock inputs and " $Q$ " and " $Q$ " outputs. These devices can be used for shift register applications, and by connecting " Q " output to the data input, for counter and toggle applications. The logic level present at the " $D$ " input is transferred to the Q output during the positive-going transition of the clock pulse. Setting or resetting is independent of the clock and is accomplished by a high level on the set or reset line respectively.

Features
Wide supply voltage range
3.0 V to 15 V

- High noise immunity
$0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
- Low power TTL compatibility
fan out of 2 driving 74L or 1 driving 74LS


## Applications

| - Automotive | - Alarm system |
| :---: | :---: |
| - Data terminals | - Industrial electronics |
| - Instrumentation | a Remote metering |
| Medical electronics | 龱 Computers |

## Connection Diagram

Dual-In-Line and Flat Package


## Truth Table

| CL ${ }^{\text {+ }}$ | D | R | S | 0 | $\overline{\mathbf{o}}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\Gamma$ | 0 | 0 | 0 | 0 | 1 |
| $\Gamma$ | 1 | 0 | 0 | 1 | 0 |
| 2 | x | 0 | 0 | 0 | $\overline{0}$ |
| $\times$ | $\times$ | 1 | 0 | 0 | 1 |
| x | x | 0 | 1 | 1 | 0 |
| $x$ | $\times$ | 1 | 1 | 1 | 1 |

No change
$\dagger=$ Level change
$x=$ Don't care case

Absolute Maximum Ratings
(Notes 1 and 2)
$V_{D D}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{S}}$ Storage Temperature Range
PD Package Dissipation
TL Lead Temperature (Soldering, 10 seconds)
-0.5 to $+18 V_{D C}$
-0.5 to $V_{D D}+0.5 V_{D C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$300^{\circ} \mathrm{C}$
(Note 2)
$V_{D D}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4013BM CD4013BC
+3 to $+15 V_{D C}$ 0 to $V_{D D} V_{D C}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## DC Electrical Characteristics 4013BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 V \\ & V_{D D}=10 V \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 1.0 |  |  | 1.0 |  | 30 | $\mu \mathrm{A}$ |
|  |  |  |  | 2.0 |  |  | 2.0 |  | 60 | $\mu \mathrm{A}$ |
|  |  |  |  | 4.0 |  |  | 4.0 |  | 120 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | ${ }^{11} \mathrm{O} \mid<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $\mid \mathrm{I}_{\mathrm{O}} \mathrm{l}<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 |  |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 |  |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 |  |  | 14.95 |  | V |
| VIL | 'Low Level Input Voltage | ${ }^{1} \mathrm{O}_{\mathrm{O}} \mathrm{l}<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | v |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V}$ |  | $3.0$ |  |  | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | v |
| $V_{I H}$ | High Level Input Voltage | $\left\|{ }_{\mathrm{O}}\right\|<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 |  |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | $\checkmark$ |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 |  |  | 0.36 |  | $\mathrm{mA}$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 | - | 0.9 |  | $\mathrm{mA}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| IOH | High !-svel Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | $-1.6$ | . | $-1.3$ | -2.25 |  | $-0.9$ |  | $m \mathrm{~A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | $-4.2$ |  | -3.4 | -8.8 |  | $-2.4$ |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{1 N}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

## DC Electrical Characteristics 4013BC (Note 2)

| PARAMETER |  | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | min | TYP | MAX | MIN | MAX |  |
| IDD | Quiesce., Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 4.0 |  |  | 4.0 |  | 30 | $\mu \mathrm{A}$ |
|  |  |  |  | 8.0 |  |  | 8.0 |  | 60 | $\mu \mathrm{A}$ |
|  |  |  |  | 16.0 |  |  | 16.0 |  | 120 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $11 \mathrm{O} \mid<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $\\| \mathrm{O} \mid<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 |  |  | 4.95 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 |  |  | 9.95 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 |  |  | 14.95 |  | $v$ |
| $V_{\text {IL }}$ | Low Level Input Voitage | $\\|{ }^{\prime} \mathrm{O} \mid<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | v |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V}$ |  | 3.0 |  |  | 3.0 |  | 3.0 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | $v$ |

DC Electrical Characteristics (Cont'd.) CD4013BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| VIH | High Level Input Voltage |  | $\\|_{0} \mathrm{l}<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | V |
|  |  | $\mathrm{V}_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 |  |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | V |
| ${ }^{1} \mathrm{OL}$ | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=13.5 \mathrm{~V}$ | $-3.6$ |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1 N}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}$, unless otherwise noted

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| CLOCK OPERATION |  |  |  |  |  |
| tPHL, or Propagation Delay Time | $V_{D D}=5 \mathrm{~V}$ |  | 200 | 350 | ns |
| ${ }_{\text {tPLH }}$ | $V_{D D}=10 \mathrm{~V}$ |  | 80 | 160 | ns |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 65 | 120 | ns |
| tthl. or Transition Time | $\mathrm{V}_{\text {DD }}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
| ${ }^{\text {tTLH }}$ | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| twL. or Minimum Clock Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
| ${ }^{\text {twh }}$ | $V_{D D}=10 \mathrm{~V}$ |  | 40 | 80 | ns |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 32 | 65 | ns |
| ${ }^{\text {tr }}$ CL, ${ }^{\text {t }}$ FCL Maximum Clock Rise and Fall Time | $V_{D D}=5 \mathrm{~V}$ |  |  | . 15 | $\mu \mathrm{s}$ |
|  | $V_{D D}=10 \mathrm{~V}$ |  |  | 10 | $\mu \mathrm{s}$ |
|  | $V_{D D}=15 \mathrm{~V}$ |  |  | 5 | $\mu \mathrm{s}$ |
| tsu Minimum Set-Up Time | $V_{D D}=5 \mathrm{~V}$ |  | 20 | 40 | ns |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 15 | 30 | ns |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 12 | 25 | ns |
| fCL Maximum Clock Frequency | $V_{D D}=5 \mathrm{~V}$ | 2.5 | 5 |  | MHz |
|  | $V_{D D}=10 \mathrm{~V}$ | 6.2 | 12.5 |  | MHz |
|  | $V_{D D}=15 \mathrm{~V}$ | 7.6 | 15.5 |  | MHz |
| SET AND RESET OPERATION |  |  |  |  |  |
| Propagation Delay Time | $V_{\text {DD }}=5 \mathrm{~V}$ |  | 150 | 300 | ns |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 65 | 130 | ns |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 45 | 90 | ns |
| tWH(R). Minimum Set and Reset | $V_{D D}=5 \mathrm{~V}$ |  | 90 | 180 | ns |
| tWH(S) Pulse Width | $V_{D D}=10 \mathrm{~V}$ |  | 40 | 80 | ns |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 25 | 50 | ns |
| CIN Average Input Capacitance | Any Input |  | 5 | 7.5 | pF |



all n.substrates $1 \underset{-}{\text { ! }}$ connected to vos

## Logic Diagram



## Switching Time Waveforms



## National Semiconductor <br> CD4014BM/CD4014BC 8-Stage Static Shift Register

## General Description

The CD4014BM/CD4014BC is an 8-stage parallel input/ serial output shift register. A parallel/serial control input enables individual JAM inputs to each of 8 stages. Q outputs are available from the sixth, seventh and eighth stages. All outputs have equal source and sink current capabilities and conform to standard "B" series output drive.

When the parallel/serial control input is in the logical " 0 " state, data is serially shifted into the register synchronously with the positive transition of the clock. When the parallel/serial control input is in the logical " 1 " state, data is jammed into each stage of the register synchronously with the positive transition of the clock.

All inputs are protected against static discharge with diodes to $V_{D D}$ and $V_{S S}$.

## Features

- Wide supply voltage range-3.0V to 15 V
- High noise immunity $-0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
- Low power TTL compatibility - fan out of 2 driving 74 L or 1 driving 74LS
- $5 \mathrm{~V}-10 \mathrm{~V}-15 \mathrm{~V}$ parametric ratings

是 Symmetrical output characteristics

- Maximum input leakage $1 \mu \mathrm{~A}$ at 15 V over full temperature range

Connection Diagram
Dual-In-Line Package


## Truth Table

| CL* | Serial Input | Parallell <br> Serial <br> Control | Pl1 | PIn | Q1 <br> (Internal) | $Q_{n}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| - | $x$ | 1 | 0 | 0 | 0 | 0 |
| $\checkmark$ | X | 1 | 1 | 0 | 1 | 0 |
| $\square$ | X | 1 | 0 | 1 | 0 | 1 |
| $\square$ | $x$ | 1 | 1 | 1 | 1 | 1 |
|  | 0 | 0 | $x$ | $x$ | 0 | $Q_{n-1}$ |
| $\square$ | 1 | 0 | $x$ | $x$ | 1 | $Q_{n-1}$ |
| $\bigcirc$ | X | X | X | X | Q1 | $Q_{n}$ |

*Level change
$X=$ Don't care case


Absolute Maximum Ratings
(Notes 1 \& 2)
$V_{D D}$ Supply Voltage
-0.5 to +18 V
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{S}}$ Storage Temperature Range
$P_{D} \quad$ Package Dissipation
IL Lead Temperature (Soldering, 10 sec .) $300^{\circ} \mathrm{C}$

Recommended Operating Conditions
(Note 2)
$V_{D D}$ Supply Voltage
3.0 to 15 V 0 to $V_{D D}$
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range
CD4014BM
CD4014BC
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$

DC Electrical Characteristics (Note 2) - CD4014BM

| Parameter |  | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Typ | Max | Min | Max |  |
| $I_{\text {DD }}$ | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 5 \\ 10 \\ 20 \end{gathered}$ |  | $\begin{aligned} & 0.1 \\ & 0.2 \\ & 0.3 \end{aligned}$ | $\begin{gathered} 5 \\ 10 \\ 20 \end{gathered}$ |  | $\begin{aligned} & 150 \\ & 300 \\ & 600 \end{aligned}$ | $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $\left.\begin{array}{l} V_{D D}=5 \mathrm{~V} \\ V_{D D}=10 \mathrm{~V} \\ V_{D D}=15 \mathrm{~V} \end{array}\right\}\left\|I_{O}\right\|<1 \mu \mathrm{~A}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \\ & 0.05 \end{aligned}$ |  | $\begin{aligned} & 0 \\ & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & 0.05 \\ & 0.05 \\ & 0.05 \end{aligned}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \\ & 0.05 \end{aligned}$ | $\begin{aligned} & v \\ & v \\ & v \end{aligned}$ |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\left.\begin{array}{l} V_{D D}=5 \mathrm{~V} \\ V_{D D}=10 \mathrm{~V} \\ V_{D D}=15 \mathrm{~V} \end{array}\right\}\left\|I_{O}\right\|<1 \mu \mathrm{~A}$ | $\begin{gathered} 4.95 \\ 9.95 \\ 14.95 \end{gathered}$ |  | 4.95 9.95 14.95 | 5 10 15 |  | $\begin{gathered} 4.95 \\ 9.95 \\ 14.95 \end{gathered}$ |  | $\begin{aligned} & v \\ & v \\ & v \end{aligned}$ |
| $V_{\text {IL }}$ | Low Level Input Voltage | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{O}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V} \\ & \mathrm{~V}_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V} \\ & \mathrm{~V}_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V} \text { or } 13.5 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ |  | $\begin{aligned} & 2 \\ & 4 \\ & 6 \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ | $\begin{aligned} & v \\ & v \\ & v \end{aligned}$ |
| $\mathrm{V}_{\mathrm{iH}}$ | High Level Input Voltage | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{O}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V} \\ & \mathrm{~V}_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V} \text { or } 13.5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 3.5 \\ 7.0 \\ 11.0 \end{gathered}$ |  | $\begin{gathered} 3.5 \\ 7.0 \\ 11.0 \end{gathered}$ | 3 6 9 |  | $\begin{gathered} 3.5 \\ 7.0 \\ 11.0 \end{gathered}$ |  | $\begin{aligned} & V \\ & v \\ & v \end{aligned}$ |
| IOL | Low Level Output Current | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 0.64 \\ 1.6 \\ 4.2 \end{gathered}$ |  | 0.51 1.3 3.4 | $\begin{gathered} 0.88 \\ 2.2 \\ 8 \end{gathered}$ |  | $\begin{gathered} 0.36 \\ 0.90 \\ 2.4 \end{gathered}$ |  | mA <br> mA <br> mA |
| $\mathrm{IOH}^{\text {O }}$ | High Level Output Current | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{O}=4.6 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{O}=9.5 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=13.5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} -0.64 \\ -1.6 \\ -4.2 \end{gathered}$ |  | -0.51 -1.3 -3.4 | $\begin{gathered} -0.88 \\ -2.2 \\ -8 \end{gathered}$ |  | $\begin{array}{r} -0.36 \\ -0.90 \\ -2.4 \end{array}$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $I_{\text {IN }}$ | Input Current | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} -0.10 \\ 0.10 \end{gathered}$ |  | $\begin{gathered} -10^{-5} \\ 10^{-5} \end{gathered}$ | $\begin{gathered} -0.10 \\ 0.10 \end{gathered}$ |  | $\begin{gathered} -1.0 \\ 1.0 \end{gathered}$ | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |

DC Electrical Characteristics (Note 2) - CD4014BC

| Parameter |  | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Typ | Max | Min | Max |  |
| $I_{D D}$ | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 20 |  | 0.1 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  |  |  | 40 |  | 0.2 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  |  |  | 80 |  | 0.3 | 80 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $\left.V_{D D}=10 \mathrm{~V}\right\}\left\|I_{0}\right\|<1 \mu \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 V$ |  |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $\left.V_{D D}=10 \mathrm{~V}\right\}\left\|\left.\right\|_{0}\right\|<1 \mu \mathrm{~A}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6 | 4.0 |  | 4.0 | V |
| $V_{1 H}^{\prime}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 3 |  | 3.5 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 6 |  | 7.0 |  | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 9 |  | 11.0 |  | V |
| $\mathrm{IOL}^{\text {L }}$ | Low Level Output Current | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  |  |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.2 |  | 0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8 |  | 2.4 |  | mA |
| $\mathrm{IOH}^{\text {OH}}$ | High Level Output Current | $\mathrm{V}_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | $-0.36$ |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.2 |  | -0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | $-3.0$ | -8 |  | -2.4 |  | mA |
| $\mathrm{I}_{\mathrm{N}}$ | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}$, input $t_{r}, t_{f}=20 \mathrm{~ns}, C_{L}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k} \Omega$

| Parameter |  | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {PLH }}, \mathrm{t}_{\text {PHL }}$ | Propagation Delay Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 200 80 60 | $\begin{aligned} & 320 \\ & 160 \\ & 120 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {THL }}, t_{\text {TLH }}$ | Transition Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 100 50 40 | $\begin{gathered} 200 \\ 100 \\ 80 \end{gathered}$ |  |
| $f_{C L}$ | Maximum Clock Input Frequency | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 2.8 \\ 6 \\ 8 \end{gathered}$ | $\begin{gathered} 4 \\ 12 \\ 16 \end{gathered}$ |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $t_{\text {w }}$ | Minimum Clock Pulse Width | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 90 \\ & 40 \\ & 25 \end{aligned}$ | $\begin{gathered} 180 \\ 80 \\ 50 \end{gathered}$ |  |
| $\mathrm{tr}_{\mathrm{r}} \mathrm{CL}, \mathrm{t}_{\mathrm{f}} \mathrm{CL}$ | Clock Rise and Fall Time (Note 3) | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{aligned}$ |  |  | $\begin{array}{r} 15 \\ 15 \\ 15 \end{array}$ | $\mu \mathrm{S}$ $\mu \mathrm{S}$ $\mu \mathrm{S}$ |
| $\mathrm{t}_{\text {s }}$ | Minimum Set-up Time (Note 5) <br> Serial Input $t_{H} \geq 200 \mathrm{~ns}$ | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 60 40 30 | $\begin{aligned} & 120 \\ & 80 \\ & 60 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
|  | Parallel Inputs $\mathrm{t}_{\mathrm{H}} \geq 200 \mathrm{~ns}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{aligned}$ |  | 80 40 30 | $\begin{aligned} & 160 \\ & 80 \\ & 60 \end{aligned}$ |  |
|  | Parallel/Serial Control $\mathrm{t}_{\mathrm{H}} \geq 200 \mathrm{~ns}$ | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 100 50 40 | $\begin{gathered} 200 \\ 100 \\ 80 \end{gathered}$ |  |
| $t_{\text {H }}$ | Minimum Hold Time Serial In, Parallel In, $\mathrm{t}_{\mathrm{s}} \geq 400 \mathrm{~ns}$ Parallel/Serial Control | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{aligned}$ |  |  | $\begin{gathered} 0 \\ 10 \\ 15 \end{gathered}$ | ns <br> ns ns |
| $\begin{aligned} & \mathrm{C}_{1} \\ & \mathrm{C}_{\mathrm{PD}} \end{aligned}$ | Average Input Capacitance <br> Power Dissipation Capacitance (Note 4) | Any Input |  | $\begin{gathered} 5 \\ 110 \end{gathered}$ | 7.5 | $\begin{aligned} & \mathrm{pF} \\ & \mathrm{pF} \end{aligned}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: If more than one unit is cascaded $t_{r} C L$ should be made less than or equal to the fixed propagation delay of the output of the driving stage for the estimated capacitive load.
Note 4: CPD determines the no load AC power consumption of any CMOS device. For complete explanation, see 54C/74C family characteristics application note AN-90.
Note 5: Set-up times are measured with reference to clock and a fixed hold time ( $\mathrm{t}_{\mathrm{H}}$ ) as specified.

Typical Performance Characteristics





National Semiconductor

## CD4015BM/CD4015BC DUAL 4-BIT Static Shift Register

## General Description

The CD4015BM/CD4015BC contains two identical, 4-stage, serial-input/parallel-output registers with independent "Data," "Clock," and "Reset" inputs. The logic level present at the input of each stage is transferred to the output of that stage at each positive-going clock transition. A logic high on the "Reset" input resets all four stages covered by that input. All inputs are protected from static discharge by a series resistor and diode clamps to VDD and VSS.

## Features

- Wide supply voltage range
- High noise immunity

| Low power TTL compatibility | fan out of 2 driving 74L or 1 driving 74LS |
| :---: | :---: |
| - Medium speed operation | 8 MHz (typ) clock rate |
| - Fully static design | $@ V_{\text {DD }}-\mathrm{V}_{\text {SS }}=10$ Volts |

## Applications

- Serial-input/parallel-output data queueing
- Serial to parallel data conversion
- General purpose register


## Connection Diagram and Truth Table




- Level change

X Don't care case.

Logic Diagrams


Absolute Maximum Ratings (Notes 1 and ${ }^{2)}$

| $V_{D D}$ | DC Supply Voltage | -0.5 to $+18 V_{D C}$ |
| :--- | :--- | ---: |
| $V_{I N}$ | Input Voltage | -0.5 to $V_{D D}+0.5 \mathrm{~V}_{\mathrm{DC}}$ |
| TS | Storage Temperature Range | -65 to $+150^{\circ} \mathrm{C}$ |
| PD | Package Dissipation | 500 mW |
| TL $^{2}$ | Lead Temperature (Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ |

## Recommended Operating Conditions

VDD DC Supply Voltage
VIN Input Voltage
TA Operating Temperature Range

CD4015BM
CD4015BC

$$
+3 \text { to }+15 \mathrm{~V}_{\mathrm{DC}}
$$

$$
0 \text { to } V_{D D} V_{D C}
$$

$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

DC Electrical Characteristics (Note 2) - CD4015BM

| Parameter |  | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Typ | Max | Min | Max |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 5 |  | 0.005 | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  | 0.010 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  | 0.015 | 20 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| VOH | High LevelOutput Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | $v$ |
| VIL | Low Level Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | v |
|  |  | $\mathrm{V}_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | v |
|  |  | $\mathrm{V}_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | $v$ |
| $\mathrm{V}_{1 \mathrm{H}}$ | High Level Input Voltage | $\mathrm{V}_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$; or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | v |
|  |  | $\mathrm{V}_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | v |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{0}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{0}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| In | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ |  | -0.1 |  | -10-5 | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=15 \mathrm{~V}$ |  | 0.1 |  | 10-5 | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

DC Electrical Characteristics (Note 2) - CD4015BC

| Parameter |  | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Typ | Max | Min | Max |  |
| IDD | Quiescent |  | $V \mathrm{DD}=5 \mathrm{~V}$ |  | 20 |  | 0.005 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  | Device Current | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.010 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 0.015 | 80 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | Output Voltage | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| VOH | High Level | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  | Output Voltage | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  | Input Voltage | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{\text {IH }}$ | High Level | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$; or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  | Input Voltage | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| IOL | Low Level | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  | Output Current | $\mathrm{V}_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  | Output Current | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | $-3.6$ |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| IN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | -10-5 | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | 10-5 | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.

Note 2: $\mathrm{V}_{\mathrm{SS}}=\mathrm{OV}$ unless otherwise specified.

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{~K}, \mathrm{t}_{\mathrm{I}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified.

| Clocked Operation | Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {PHL }}, t_{\text {PLH }}$ | Propogation Delay Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 230 \\ 80 \\ 60 \end{gathered}$ | $\begin{aligned} & 350 \\ & 160 \\ & 120 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {THL }}, t_{\text {TLH }}$ | Transition Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 50 \\ & 40 \end{aligned}$ | $\begin{gathered} 200 \\ 100 \\ 40 \end{gathered}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {WL }}$, tWM | Minimum Clock Pulse-Width | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 160 \\ & 60 \\ & 50 \end{aligned}$ | $\begin{aligned} & 250 \\ & 110 \\ & 100 \end{aligned}$ | ns <br> ns <br> ns |
| $\mathrm{tr}_{\mathrm{r} C L}, \mathrm{t}_{\mathrm{fCL}}$ | Clock Rise and Fall Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 15 \\ & 15 \\ & 15 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \\ & \mu \mathrm{~S} \end{aligned}$ |
| tsu | Minimum Data Set-Up Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 20 \\ & 15 \end{aligned}$ | $\begin{aligned} & 100 \\ & 40 \\ & 30 \end{aligned}$ | ns <br> ns <br> ns |
| ${ }^{\text {f }} \mathrm{CL}$ | Maximum Clock Frequency | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 2 \\ 4.5 \\ 6 \end{gathered}$ | $\begin{gathered} 3.5 \\ 8 \\ 11 \end{gathered}$ |  | MHz <br> MHz <br> MHz |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Clock Input Other Inputs |  | $\begin{gathered} 7.5 \\ 5 \end{gathered}$ | $\begin{aligned} & 10 \\ & 7.5 \end{aligned}$ | $\begin{aligned} & \mathrm{pF} \\ & \mathrm{pF} \end{aligned}$ |

Reset Operation

| ${ }^{\text {tPHL(R) }}$ | Propogation Delay Time | $V_{D D}=5 \mathrm{~V}$ | 200 | 400 | ns |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 100 | 200 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 80 | 160 | ns |
| ${ }^{\text {twh(R) }}$ | Minimum Reset Pulse Width | $V_{D D}=5 \mathrm{~V}$ | 135 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 40 | 80 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 30 | 60 | ns |

## CD4016BM/CD4016BC Quad Bilateral Switch

## General Description

The CD4016BM/CD4016BC is a quad bilateral switch intended for the transmission or multiplexing of analog or digital signals. It is pin-for-pin compatible with CD4066BM/CD4066BC.

## Features



|  | Extremely high control input impedance | $10^{12} \Omega$ (typ.) |
| :---: | :---: | :---: |
| - | Low crosstalk between switches | -50 dB (typ.) |
|  | @ $\mathrm{f}_{\mathrm{IS}}=0.9 \mathrm{MHz}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ |  |
|  | Frequency response, switch "ON" | 40 MHz (typ.) |

## Applications

- Analog signal switching/multiplexing
- Signal gating
- Squelch control
- Chopper
- Modulator/Demodulator
- Commutating switch
- Digital signal switching/multiplexing
- CMOS logic implementation
- Anal- - -to-digital/digital-to-analog conversion
- Digital control of frequency, impedance, phase, and analog-signal gain

Schematic and Connection Diagrams

Dual-In-Line Package


Absolute Maximum Ratings (Notes 1 and 2 )
$V_{D D}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
$T_{S}$ Storage Temperature Range
$P_{D}$ Package Dissipation
Lead Temperature (Soldering, 10 seconds)
-0.5 V to +18 V
-0.5 V to $\mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}$ $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW $300^{\circ} \mathrm{C}$

Recommended Operating Conditions (Note 2)
$V_{D D}$ Supply Voltage
3 V to 15 V
$V_{I N}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4016BM CD4016BC
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## DC Electrical Characteristics CD4016BM (Note 2)

| Parameter |  | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.25 |  | 0.01 | 0.25 |  | 7.5 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.5 |  | 0.01 | 0.5 |  | 15 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 1.0 |  | 0.01 | 1.0 |  | 30 | $\mu \mathrm{A}$ |

Signal Inputs and Outputs


## Control Inputs

| VILC | Low Level Input Voltage | $\begin{aligned} & V_{I S}=V_{S S} \text { and } V_{D D} \\ & V_{O S}=V_{D D} \text { and } V_{S S} \\ & I_{I S}= \pm 10 \mu \mathrm{~A} \\ & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.9 \\ & 0.9 \\ & 0.9 \end{aligned}$ |  |  | $\begin{aligned} & 0.7 \\ & 0.7 \\ & 0.7 \end{aligned}$ |  | $\begin{aligned} & 0.5 \\ & 0.5 \\ & 0.5 \end{aligned}$ | V V |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{IHC}}$ | High Level Input Voltage | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ <br> (see Note 6 ard <br> Figure 8) | $\begin{gathered} 3.5 \\ 7.0 \\ 11.0 \end{gathered}$ |  | $\begin{gathered} 3.5 \\ 7.0 \\ 11.0 \end{gathered}$ |  |  | $\begin{gathered} 3.5 \\ 7.0 \\ 11.0 \end{gathered}$ |  | V V V |
| $I_{\text {IN }}$ | Input Current | $\begin{aligned} & V_{D D}-V_{S S}=15 \mathrm{~V} \\ & V_{D D} \geqslant V_{I S} \geqslant V_{S S} \\ & V_{D D} \geqslant V_{C} \geqslant V_{S S} \end{aligned}$ |  | $\pm 0.1$ |  | $\pm 10^{-5}$ | $\pm 0.1$ |  | $\pm 1.0$ | $\mu \mathrm{A}$ |

\begin{tabular}{|c|c|c|c|c|c|c|c|c|c|c|}
\hline \multicolumn{11}{|l|}{DC Electrical Characteristics CD4016BC (Note 2)} \\
\hline \multicolumn{2}{|r|}{\multirow{2}{*}{Parameter}} \& \multirow{2}{*}{Conditions} \& \multicolumn{2}{|r|}{\(-40^{\circ} \mathrm{C}\)} \& \multicolumn{3}{|c|}{\(25^{\circ} \mathrm{C}\)} \& \multicolumn{2}{|l|}{\(85^{\circ} \mathrm{C}\)} \& \multirow[t]{2}{*}{Units} \\
\hline \& \& \& Min. \& Max. \& Min. \& Typ. \& Max. \& Min. \& Max. \& \\
\hline \(\mathrm{I}_{\mathrm{DD}}\) \& Quiescent Device Current \& \[
\begin{aligned}
\& V_{D D}=5 \mathrm{~V} \\
\& V_{D D}=10 \mathrm{~V} \\
\& V_{D D}=15 \mathrm{~V}
\end{aligned}
\] \& . \& \[
\begin{aligned}
\& 1.0 \\
\& 2.0 \\
\& 4.0
\end{aligned}
\] \& \& \[
\begin{aligned}
\& \hline 0.01 \\
\& 0.01 \\
\& 0.01 \\
\& \hline
\end{aligned}
\] \& \[
\begin{aligned}
\& 1.0 \\
\& 2.0 \\
\& 4.0 \\
\& \hline
\end{aligned}
\] \& \& \[
\begin{aligned}
\& 7.5 \\
\& 15 \\
\& 30
\end{aligned}
\] \& \begin{tabular}{l}
\(\mu \mathrm{A}\) \\
\(\mu \mathrm{A}\) \\
\(\mu \mathrm{A}\)
\end{tabular} \\
\hline \multicolumn{11}{|l|}{Signal Inputs and Outputs} \\
\hline \begin{tabular}{l}
\(\mathrm{R}_{\mathrm{ON}}\) \\
\(\Delta R_{\text {ON }}\) Is
\end{tabular} \& \begin{tabular}{l}
"ON" Resistance \\
\(\Delta\) "ON" Resistance (Between any 2 of 4 Switches (In Same Package) \\
Input or Output Leakage Switch "OFF"
\end{tabular} \& \[
\begin{aligned}
\& R_{L}=10 \mathrm{k} \Omega \text { to } \frac{V_{D D}-V_{S S}}{2} \\
\& V_{C}=V_{D D}, V_{I S}=V_{S S} \text { or } V_{D D} \\
\& V_{D D}=10 \mathrm{~V} \\
\& V_{D D}=15 \mathrm{~V} \\
\& R_{L}=10 \mathrm{k} \Omega \text { to } \frac{V_{D D}-V_{S S}}{2} \\
\& V_{C}=V_{D D} \\
\& V_{D D}=10 \mathrm{~V}, V_{I S}=4.75 \text { to } 5.25 \mathrm{~V} \\
\& V_{D D}=15 \mathrm{~V}, V_{I S}=7.25 \text { to } 7.75 \mathrm{~V} \\
\& R_{L}=10 \mathrm{k} \Omega \text { to } \frac{V_{D D}-V_{S S}}{2} \\
\& V_{C C}=V_{D D}, V_{I S}=V_{S S} \text { to } V_{D D} \\
\& V_{D D}=10 \mathrm{~V} \\
\& V_{D D}=15 \mathrm{~V} \\
\& V_{C}=0, V_{D D}=15 \mathrm{~V} \\
\& V_{I S}=0 \mathrm{~V} \text { or } 15 \mathrm{~V} \\
\& V_{O S}=15 \mathrm{~V} \text { or } 0 \mathrm{~V}
\end{aligned}
\] \& \& \begin{tabular}{l}
610 \\
370 \\
1900 \\
790 \\
\(\pm 50\)
\end{tabular} \& \& 275
200

850
400

15
10

$\pm 0.1$ \& | 660 |
| :--- |
| 400 |
| 2000 |
| 850 |
| $\pm 50$ | \& \& | 840 |
| :--- |
| 520 |
| 2380 |
| 1080 |
| $\pm 200$ | \& | $\Omega$ $\Omega$ |
| :--- |
| $\Omega$ |
| $\Omega$ |
| $\Omega$ |
| $\Omega$ |
| nA | <br>

\hline \multicolumn{11}{|l|}{Control Inputs} <br>

\hline \multicolumn{2}{|l|}{VILC Low Level Input Voltage} \& $$
\begin{aligned}
& V_{I S}=V_{S S^{\prime}} \text { and } V_{D D} \\
& V_{O S}=V_{D D} \text { and } V_{S S} \\
& I_{I S}= \pm 10 \mu \mathrm{~A} \\
& V_{D D}=5 \mathrm{~V} \\
& V_{D D}=10 \mathrm{~V} \\
& V_{D D}=15 \mathrm{~V}
\end{aligned}
$$ \& \& \[

$$
\begin{aligned}
& 0.9 \\
& 0.9 \\
& 0.9
\end{aligned}
$$

\] \& \& \& \[

$$
\begin{aligned}
& 0.7 \\
& 0.7 \\
& 0.7
\end{aligned}
$$

\] \& \& \[

$$
\begin{aligned}
& 0.4 \\
& 0.4 \\
& 0.4
\end{aligned}
$$

\] \& \[

$$
\begin{aligned}
& V \\
& V \\
& V
\end{aligned}
$$
\] <br>

\hline $\mathrm{V}_{\mathrm{IHC}}$ \& High Level Input Voltage \& \[
$$
\begin{array}{lr}
V_{D D}=5 \mathrm{~V} & \\
\mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V} & \text { (see Note } 6 \text { and } \\
\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V} & \text { Figure } 8 \text { ) }
\end{array}
$$

\] \& \[

$$
\begin{gathered}
3.5 \\
7.0 \\
11.0
\end{gathered}
$$

\] \& \& \[

$$
\begin{gathered}
3.5 \\
7.0 \\
11.0
\end{gathered}
$$

\] \& \& \& \[

$$
\begin{gathered}
3.5 \\
7.0 \\
11.0
\end{gathered}
$$

\] \& \& \[

$$
\begin{aligned}
& V \\
& V \\
& V
\end{aligned}
$$
\] <br>

\hline $\mathrm{I}_{\mathrm{IN}}$ \& Input Current \& $$
\begin{aligned}
& V_{C C}-V_{S S}=15 \mathrm{~V} \\
& V_{D D} \geqslant V_{I S} \geqslant V_{S S} \\
& V_{D D} \geqslant V_{C} \geqslant V_{S S}
\end{aligned}
$$ \& \& $\pm 0.3$ \& \& $\pm 10^{-5}$ \& $\pm 0.3$ \& \& $\pm 1.0$ \& $\mu \mathrm{A}$ <br>

\hline
\end{tabular}

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$ and $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {PHL }}, \mathrm{t}_{\text {PLH }}$ | Propagation Delay Time Signal Input to Signal Output | $\begin{aligned} & \mathrm{V}_{\mathrm{C}}=\mathrm{V}_{\mathrm{DD}}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \text { (Figure 1) } \\ & \mathrm{R}_{\mathrm{L}}=200 \mathrm{k} \\ & \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 58 \\ & 27 \\ & 20 \end{aligned}$ | $\begin{gathered} 100 \\ 50 \\ 40 \end{gathered}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {PZH, }} \mathrm{t}_{\text {PZL }}$ | Propagation Delay Time Control Input to Signal Output High Impedance to Logical Level | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=1.0 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \text {, (Figures } 2 \\ & \text { and } 3 \text { ) } \\ & \mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 20 \\ & 18 \\ & 17 \end{aligned}$ | $\begin{aligned} & 50 \\ & 40 \\ & 35 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {PHZ }}$, tplz | Propagation Delay Time Control Input to Signal Output Logical Level to High Impedance | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=1.0 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \text {, (Figures } 2 \\ & \text { and } 3 \text { ) } \\ & \mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 15 \\ & 11 \\ & 10 \end{aligned}$ | $\begin{aligned} & 40 \\ & 25 \\ & 22 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
|  | Sine Wave Distortion | $\begin{aligned} & \mathrm{V}_{\mathrm{C}}=\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=-5 \mathrm{~V} \\ & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega, \mathrm{~V}_{I S}=5 \mathrm{~V}_{\mathrm{P} \cdot \mathrm{P},}, \mathrm{f}=1 \mathrm{kHz}, \\ & \quad \text { (Figure 4) } \end{aligned}$ |  | 0.4 |  | \% |

## AC Electrical Characteristics (Cont'd)

$T_{A}=25^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$ and $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified

|  | Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Frequency Response - Switch "ON" (Frequency at -3 dB ) | $\begin{aligned} & V_{C}=V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=-5 \mathrm{~V}, \\ & R_{\mathrm{L}}=1 \mathrm{k} \Omega, \mathrm{~V}_{I S}=5 \mathrm{~V}_{\mathrm{P} . \mathrm{P}} \\ & 20 \log _{10} \mathrm{~V}_{\mathrm{OS}} / \mathrm{V}_{\mathrm{OS}}(1 \mathrm{kHz})-\mathrm{dB}, \\ & \text { (Figure 4) } \end{aligned}$ |  | 40 |  | $\mathrm{MHz}$ |
|  | Feedthrough - Switch "OFF" <br> (Frequency at -50 dB ) | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{C}}=\mathrm{V}_{S S}=-5 \mathrm{~V}, \\ & R_{L}=1 \mathrm{k}, \mathrm{~V}_{I S}=5 \mathrm{~V}_{\mathrm{P} \cdot \mathrm{P}} \\ & 20 \log _{10}\left(\mathrm{~V}_{\mathrm{OS}} / \mathrm{V}_{I S}\right)=-50 \mathrm{~dB}, \\ & \text { (Figure 4) } \end{aligned}$ |  | 1.25 |  | MHz |
|  | Crosstalk Between Any Two <br> Switches (Frequency at -50 dB ) | $\begin{aligned} & V_{D D}=V_{C(A)}=5 \mathrm{~V} ; \mathrm{V}_{S S}=V_{C(B)}=-5 \mathrm{~V}, \\ & R_{L}=1 \mathrm{k} \Omega, V_{I S(A)}=5 V_{P \cdot P}, \\ & \left.20 \log _{10}\left(V_{O S(B)}\right) V_{O S(A)}\right)=-50 \mathrm{~dB} \\ & \text { (Figure 5) } \end{aligned}$ |  | 0.9 |  | MHz |
|  | Crosstalk; Control Input to Signal Output | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega \\ & \mathrm{R}_{\mathrm{IN}}=1 \mathrm{k} \Omega, \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V} \text { Square Wave, } \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \quad \text { (Figure 6) } \end{aligned}$ |  | 150 |  | $m V_{\text {P.P }}$ |
|  | Maximum Control Input | $\begin{aligned} & R_{L}=1 \mathrm{k} \Omega, C_{L}=50 \mathrm{pF}, \text { ( Figure } 7 \text { ) } \\ & V_{O S(f)}=1 / 2 V_{O S}(1 \mathrm{kHz}) \\ & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 6.5 \\ & 8.0 \\ & 9.0 \end{aligned}$ |  | M. Hz <br> MHz <br> MHz |
| $\mathrm{C}_{\text {IS }}$ | Signal Input Capacitance |  |  | 4 |  | pF |
| CoS | Signal Output Capacitance | $V_{D D}=10 \mathrm{~V}$ |  | 4 |  | pF |
| $\mathrm{ClOS}^{\text {I }}$ | Feedthrough Capacitance | $\mathrm{V}_{\mathrm{C}}=0 \mathrm{~V}$ |  | 0.2 |  | pF |
| $\mathrm{Clin}^{\text {I }}$ | Control Input Capacitance |  |  | 5 | 7.5 | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $V_{S S}=0 V$ unless otherwise specified.
Note 3: These devices should not be connected to circuits with the power "ON".
Note 4: In all cases. there is approximately 5 pF of probe and jig capacitance on the output: however, this capacitance is included in $\mathrm{C}_{\mathrm{L}}$ wherever it is specified.
Note 5: $V_{I S}$ is the voltage at the in/out pin and $V_{O S}$ is the voltage at the out/in pin. $V_{C}$ is the voltage at the control input.
Note 6: If the switch input is held at $V_{D D} . V_{I H C}$ is the control input level that will cause the switch output to meet the standard " $B$ " series $\mathrm{V}_{\mathrm{OH}}$ and $\mathrm{I}_{\mathrm{OH}}$ output levels. If the analog switch input is conected to $\mathrm{V}_{\mathrm{SS}}$. $\mathrm{V}_{\mathrm{IHC}}$ is the control input level - which allows the switch to sink standard "B" series $\|\mathrm{OH}\|$, high level current, and still maintain a $\mathrm{V}_{\mathrm{OL}} \leqslant$ standard " B " series. See Figure 8.

## AC Test Circuits and Switching Time Waveforms



Figure 1. $\mathrm{t}_{\text {PHL }}, \mathrm{t}_{\text {PLH }}$ Propagation Delay Time Signal Input to Signal Output


Figure 2. $\mathrm{t}_{\mathrm{PZH}}, \mathrm{t}_{\mathrm{PHZ}}$ Propagation Delay Time Control to Signal Output

## AC Test Circuits and Switching Time Waveforms (Cont'd)



Figure 3. $\mathbf{t}_{\text {PZH }}, \mathrm{t}_{\mathrm{PHZ}}$ Propagation Delay Time Control to Signal Output

$V_{C}=V_{D D}$ for distortion and frequency response tests
$V_{C}=V_{S S}$ for feedthrough test
Figure 4. Sine Wave Distortion, Frequency Response and Feedthrough


Figure 5. Crosstalk Between Any Two Switches


Figure 6. Crosstalk - Control to Input Signal Output


Figure 7. Maximum Control Input Frequency


Figure 8. CD4016B Switch Test Conditions for $\mathrm{V}_{\mathrm{IHC}}$

## Typical Performance Characteristics

'ON' Resistance vs. Signal Voltage $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

'ON' Resistance Temperature Variation for $V_{D D}-V_{S S}=10 \mathrm{~V}$
'ON' Resistance Temperature Variation for $V_{D D}-V_{S S}=15 V$


## Typical Applications



4 Input Multiplexer


Sample/Hold Amplifier

## Special Considerations

The CD4016B is composed of 4, two-transistor analog switches. These switches do not have any linearization or compensation circuitry for "R $\mathrm{R}_{\mathrm{ON}}$ " as do the CD4066B's. Because of this, the special operating considerations for the CD4066B do not apply to the CD4016B, but at low
supply voltages, $\leqslant 5 \mathrm{~V}$, the CD4016B's on resistance becomes non-linear. It is recommended that at 5 V , voltages on the in/out pins be maintained within about 1 V of either $V_{D D}$ or $V_{S S}$; and that at $3 V$ the voltages on the in/out pins should be at $V_{D D}$ or $V_{S S}$ for reliable operation.

National Semiconductor

## CD4017BM/CD4017BC Decade Counter/Divider with 10 Decoded Outputs <br> CD4022BM/CD4022BC Divide-by-8 Counter/Divider with 8 Decoded Outputs

## General Description

The CD4017BM/CD4017BC is a 5 -stage divide-by-10 Johnson counter with 10 decoded outputs and a carry out bit.

The CD4022BM/CD4022BC is a 4 -stage divide-by- 8 Johnson counter with 8 decoded outputs and a carryout bit.

These counters are cleared to their zero count by a logical " 1 " on their reset line. These counters are advanced on the positive edge of the clock signal when the clock enable signal is in the logical " 0 " state.

The configuration of the CD4017BM/CD4017BC and CD4022BM/CD4022BC permits medium speed operation and assures a hazard free'counting sequence. The 10/8 decoded outputs are normally in the logical " 0 " state and go to the logical " 1 " state only at their respective time slot. Each decoded output remains high for 1 full clock cycle. The carry-out signal completes a full cycle for every $10 / 8$ clock input cycles and is used as a ripple carry signal to any succeeding stages.

## Features

- Wide supply voltage range
3.0 V to 15 V
- High noise immunity
- Low power

TTL compatibility

- Medium speed operation
- Low power
- Fully static operation


## Applications

- Automotive
- Instrumentation
- Medical electronics
- Alarm systems
- Industrial electronics
- Remote metering


## Connection Diagrams

CD4017B
Dual-In-Line and Flat Package


TOP VIEW

CD4022B
Dual-In-Line and Flat Package


## Absolute Maximum Ratings

(Notes 1 and 2)
VDD dc Supply Voltage
-0.5 to $+18 V_{D C}$
$V_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
-0.5 to $V_{D D}+0.5 V_{D C}$ $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
PD Package Dissipation 500 mW
$\mathrm{T}_{\mathrm{L}}$ Lead Temperature (Soldering, 10 seconds)

Recommended Operating Conditions
(Note 2)

| $V_{D D}$ dc Supply Voltage | +3 to $+15 V_{D C}$ |
| :--- | ---: |
| $V_{\text {IN }}$ Input Voltage | 0 to $V_{D D} V_{D C}$ |
| TA Operating Temperature Range CD4017BM, CD4022BM | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD4017BC, CD4022BC | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

DC Electrical Characteristics CD4017BM, CD4022BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| ${ }^{1} \mathrm{DD}$ | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 5 |  | 0.3 | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  |  |  | 10 |  | 0.5 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  |  |  | 20 |  | 1.0 | 20 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $\left\|\mathrm{I}_{\mathrm{O}}\right\|<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $\left\|\mathrm{I}_{\mathrm{O}}\right\|<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL | Low Level Input Voltage | $\left\|{ }^{0} \mathrm{O}\right\|<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | V |
|  |  | $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  |  | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | . | 4.0 |  | 4.0 | v |
| V IH | High Level Input Voltage | $\|10\|<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  |  |  |  | 3.5 |  | v |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 |  |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | $v$ |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{0}=4.6 \mathrm{~V}$ | -0.25 |  |  | , -0.36 |  | $-0.14$ |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -0.62 |  | -0.5 | -0.9 |  | -0.35 |  | $m A$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -1.8 |  | -1.5 | -3.5 |  | -1.1 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

DC Electrical Characteristics CD4017BC, CD4022BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\mathrm{V}_{\text {DD }}=5 \mathrm{~V}$ |  | 20 |  | 0.5 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 1.0 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 5.0 | 80 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\left\|{ }^{0} \mathrm{O}\right\|<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| $\mathrm{VOH}^{\text {O }}$ | High Level Output Voltage | $\\|_{0} \mathrm{l}<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | $v$ |

DC Electrical Characteristics (Cont'd.) 4017BC, 4022BC (Note 2)

| PARAMETER |  | CONDITIONS | - $40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| VIL | Low Level Input Voltage |  | $\\|_{\mathrm{O}} \mid<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  |  | 3.0 |  | 3.0 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{\text {IH }}$ | High Level Input Voltage | $H_{O} l^{\prime}<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 |  |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | V |
| ${ }^{\prime} \mathrm{OL}$ | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.2 |  | -0.16 | -0.36 |  | -0.12 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{O}=9.5 \mathrm{~V}$ | -0.5 |  | -0.4 | -0.9 |  | -0.3 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -1.4 |  | -1.2 | -3.5 |  | -1.0 |  | mA |
| 1 N | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $V_{S S}=O V$ unless otherwise specified.
AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}, \mathrm{t}_{\mathrm{rCL}}$ and $\mathrm{t}_{\mathrm{fCL}}=20 \mathrm{~ns}$, unless otherwise specified

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CLOCKED OPERATION |  |  |  |  |  |  |
| tPHL, TPLH | Propagation Delay Time: Carry Out Line |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 415 | 800 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 160 | 320 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 130 | 250 | ns |
|  | Carry Out Line | $\left.\begin{array}{l} V_{D D}=5 \mathrm{~V} \\ V_{D D}=10 \mathrm{~V} \\ V_{D D}=15 \mathrm{~V} \end{array}\right\} C_{L}=15 \mathrm{pF}$ |  | 240 | 480 | ns |
|  |  |  |  | 85 | 170 | ns |
|  |  |  |  | 70 | 140 | ns |
|  | Decode Out Lines | $V_{D D}=5 \mathrm{~V}$ |  | 500 | 1000 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 200 | 400 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 160 | 320 | ns |
| ${ }^{\text {t }}$ LLH, T THL | Transition Time Carry Out and Decode Out Lines |  |  |  |  |  |
|  | tTLH | $V_{D D}=5 V$ |  | 200 | 360 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 100 | 180 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 | 130 | ns |
|  | tTHL | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| ${ }^{\mathrm{f}} \mathrm{CL}$ | Maximum Clock Frequency | $\left.\begin{array}{l\|l}V_{D D}=5 \mathrm{~V} \\ V_{D D}=10 \mathrm{~V} \\ V_{D D}=15 \mathrm{~V}\end{array}\right\} \begin{aligned} & \text { Measured with } \\ & \text { Respect to Carry } \\ & \text { Output Line }\end{aligned}$ | $\begin{aligned} & 2.0 \\ & 5.0 \\ & 6.7 \end{aligned}$ | 2 |  | MHz |
|  |  |  |  | 5 |  | MHz |
|  |  |  |  | 6 |  | MHz |
| ${ }^{\text {tWL, }}$ 'WH | Minimum Clock Pulse | $V_{D D}=5 \mathrm{~V}$ |  | 125 | 250 | ns |
|  | Width | $V_{D D}=10 \mathrm{~V}$ |  | 45 | 90 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 35 | 70 | ns |
| $\mathrm{tr}_{\mathrm{r}} \mathrm{CL}, \mathrm{tfCL}$ | Clock Rise and Fall Time | $V_{D D}=5 \mathrm{~V}$ |  |  | 20 | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  |  | 15 | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | - | 5 | $\mu \mathrm{s}$ |
| ${ }^{\text {t }}$ SU | Minimum Clock Inhibit Data Set-Up Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 120 | 240 | ns |
|  |  |  |  | 40 | 80 | ns |
|  |  |  |  | 32 | 65 | ns |
| CIN | Average Input Capacitance |  |  | 5 | 7.5 | pF |

## AC Electrical Characteristics (Cont'd.)

$T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}, \mathrm{t}_{\mathrm{r}} \mathrm{CL}$ and $\mathrm{t}_{\mathrm{f} C L}=20 \mathrm{~ns}$, unless otherwise specified.


Timing Diagrams
CD4017B


## Logic Diagrams



## CD4018BM/CD4018BC Presettable Divide-by-N Counter

## General Description

The CD4018B consists of 5 Johnson counter stages. A buffered $\bar{Q}$ output from each stage, "CLOCK", "RESET", "DATA", "PRESET ENABLE", and 5 individual "JAM" inputs are provided. The counter is advanced one count at the positive clock signal transition. A high "RESET" signal clears the counters to an "ALL ZERO" condition. A high "PRESET ENABLE" signal allows information on the "JAM" inputs to preset the counter. Anti-lock gating is provided to assure the proper counting sequence.

## Features

- Wide supply voltage range
3.0 V to 15 V
- High noise immunity
- Low power TTL compatibility
$0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.) compatiblity
fan out of 2 driving 74L or 1 driving 74LS
- Fully static operation


## Applications

(1) Fixed and programmable divide-by-10, 9, 8, 7, 6, 5, 4, 3, 2 counter
in Fixed and programmable counters greater than 10
国 Programmable decade counters
풀 Divide by " $N$ " counters/frequency synthesizers

## Logic Diagram



## Connection Diagram

## Dual-In-Line and Flat Package



## Absolute Maximum Ratings (Note 1)

(Notes 1 and 2)
$V_{D D}$ dc Supply Voltage
VIN Input Voltage
TS Storage Temperature Range
$P_{D}$ Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
-0.5 to $+18 V_{D C}$
-0.5 to $V_{D D}+0.5 V_{D C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW $300^{\circ} \mathrm{C}$

Recommended Operating Conditions (Note 2)

| $V_{D D}$ dc Supply Voltage | 3 to $15 V_{D C}$ |
| :--- | ---: |
| $V_{\text {IN }}$ Input Voltage | 0 to $V_{D D} V_{D C}$ |
| $T_{A}$ Operating Temperature Range |  |
| CD4018BM | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD4018BC | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

DC Electrical Characteristics CD4018BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | 5 <br> 10 <br> 20 |  |  | $0.3$ | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $0.5$ |  |  |  | 10 |  | 300 | $\mu \mathrm{A}$ |  |
|  |  | $1.0$ |  |  |  | 20 |  | 600 | $\mu \mathrm{A}$ |  |
| VOL | Low Level Output Voltage | $\begin{aligned} & \left\|I_{O}\right\|<1 \mu \mathrm{~A} \\ & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4.95 \\ & 9.95 \\ & 14.95 \end{aligned}$ |  |  |  |  |  |  |  |
|  |  |  |  | 0.05 | 0 |  | 0.05 |  | 0.05 | V |
|  |  |  |  | 0.05 | 0 |  | 0.05 |  | 0.05 | V |
|  |  |  |  | 0.05 | 0 |  | 0.05 |  | 0.05 | V |
| VOH | High Level Output Voltage | $\begin{aligned} & \left\|I_{O}\right\|<1 \mu \mathrm{~A} \\ & \mathrm{~V}_{D D}=5 \mathrm{~V} \\ & \mathrm{~V}_{D D}=10 \mathrm{~V} \\ & \mathrm{~V}_{D D}=15 \mathrm{~V} \end{aligned}$ |  |  |  |  |  |  |  |  |  |
|  |  |  |  |  | 4.95 |  | 5 |  | 4.95 |  | V |
|  |  |  |  |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  |  |  |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $V_{\text {IH }}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{O}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| ${ }^{1} \mathrm{OL}$ | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| ${ }^{\mathrm{I} O H}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

DC Electrical Characteristics CD4018BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 20 |  | 0.5 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  |  |  | 40 |  | 1.0 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  |  |  | 80 |  | 5.0 | 80 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\\|_{O} \mid<1 \mu \mathrm{~A}$ |  |  |  |  |  | . |  |  |
|  |  | $V_{D D}=5 V$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\left\|\mathrm{O}^{\prime}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | $V$ |
| VIL | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | $\checkmark$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | $\checkmark$ |
| $V_{1 H}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |

DC Electrical Characteristics
(Continued) CD4018BC

|  | PARAMETER | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IOL | Low Level Output Current | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 0.52 \\ & 1.3 \\ & 3.6 \end{aligned}$ |  | $\begin{aligned} & 0.44 \\ & 1.1 \times \\ & 3.0 \end{aligned}$ | 0.88 2.25 8.8 |  | $\begin{aligned} & 0.36 \\ & 0.9 \\ & 2.4 \end{aligned}$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \\ & \mathrm{~mA} \end{aligned}$ |
| IOH | High Level Output Current | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V} \end{aligned}$ | $\begin{array}{\|l} -0.52 \\ -1.3 \\ -3.6 \end{array}$ |  | $\begin{aligned} & -0.44 \\ & -1.1 \\ & -3.0 \end{aligned}$ | $\begin{aligned} & -0.88 \\ & -2.25 \\ & -8.8 \end{aligned}$ |  | $\begin{aligned} & -0.36 \\ & -0.9 \\ & -2.4 \end{aligned}$ |  | mA <br> mA <br> mA |
| IN | Input Current | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} -0.30 \\ 0.30 \end{array}$ |  | $\begin{array}{r} -10^{-5} \\ 10^{-5} \end{array}$ | $\begin{array}{r} -0.3 \\ 0.3 \end{array}$ |  | $\begin{array}{r} -1.0 \\ 1.0 \end{array}$ | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |

## AC Electrical Characteristics

$\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}$, Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CLOCK OPERATION |  |  |  |  |  |  |
| tPHL, tPLH | Propagation Delay Time to $\overline{\mathrm{Q}}$ | $V_{D D}=5 \mathrm{~V}$ |  | 235 | 700 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 95 | 250 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 70 | 200 | ns |
| tTHL, tTLH | Transition Time $\overline{\mathrm{Q}}$ Outputs | $V_{D D}=5 \mathrm{~V}$ |  | 125 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 65 | 130 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 50 | 100 | ns |
| twL, twh | Minimum Clock Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 125 | 500 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 200 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 160 | ns |
| ${ }^{\text {trach }}$, ${ }^{\text {FFCL }}$ | Clock Rise and Fall Time | $V_{D D}=5 \mathrm{~V}$ |  |  | 15 | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  |  | 15 | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  |  | 15 | $\mu \mathrm{s}$ |
| ${ }^{\text {t }}$ U | Minimum Data Input Set-Up Time | $V_{D D}=5 \mathrm{~V}$ |  | 40 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 20 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 16 | 80 | ns |
| ${ }^{\mathrm{f}} \mathrm{CL}$ | Maximum Clock Frequency | $V_{D D}=5 \mathrm{~V}$ | 1 | 4 |  | MHz |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 3 | 9 |  | MHz |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 5 | 14 |  | MHz |
| PRESET OR RESET OPERATION |  |  |  |  |  |  |
| tPLH(R) | Propagation Delay Time to $\overline{\mathrm{Q}}$ | $V_{D D}=5 \mathrm{~V}$ |  | 235 | 750 | ns |
| tPHL(PR) |  | $V_{D D}=10 \mathrm{~V}$ |  | 95 | 250 | ns |
| tPLH(PR) |  | $V_{D D}=15 \mathrm{~V}$ |  | 70 | 200 | ns |
| tWH(R). | Minimum Preset or Reset | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 400 | ns |
| tWH(PR) | Pulse Width | $V_{D D}=10 \mathrm{~V}$ |  | 40 | 160 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 30 | 120 | ns |
| ${ }^{\text {t REM }}$ | Minimum Preset or Reset Removal Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 400 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 | 160 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 30 | 120 | ns |
| $\mathrm{CIN}_{\text {I }}$ | Average Input Capacitance | Any Input |  | 5 | 7.5 | pF |
| CPD | Power Dissipation Capacitance | (Note 3) |  | 63 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $V_{S S}=O V$ unless otherwise specified.
Note 3: CPD determines the no load ac power consumption of any CMOS device. For complete explanation, see 54C/74C family characteristics application note AN-90.

Typical Performance Chàracteristics

## External Connections

External Connections for Divide by
10, 9, 8, 7, 6, 5, 4, 3, 2, Operation
\(\left.$$
\begin{array}{ll}\begin{array}{ll}\text { Divide By } 10 & \overline{\mathrm{Q}} 5 \\
\begin{array}{l}\text { Divide By } 8 \\
\text { Divide By } 6 \\
\text { Divide By } 4\end{array} & \overline{\overline{\mathrm{Q}}} 4 \\
\text { Divide By } 2\end{array}
$$ \& \overline{\overline{\mathrm{Q}} 2} <br>

\overline{\mathrm{Q}} 1\end{array}\right\}\)| Connected Back |
| :--- |
| To "DATA" Input |

Divide By 9


Divide By 7


Divide By 5


Divide By 3




Timing Diagram


Note. "Data" input tied to $\overline{\mathrm{Q}} 5$ for decade counter configuration.

## CD4019BM/CD4019BC Quad AND-OR Select Gate

## General Description

The CD4019BM/CD4019BC is a complementary MOS quad AND-OR select gate. Low power and high noise margin over a wide voltage range is possible through implementation of N and P -channel enhancement mode transistors. These complementary MOS (CMOS) transistors provide the building blocks for the 4 "AND-OR select" gate configurations, each consisting of two 2 -input AND gates driving a single 2 -input $O R$ gate. Selection is accomplished by control bits $K_{A}$ and $K_{B}$. All inputs are protected against static discharge damage.

## Features

- Wide supply voltage range
- High noise immunity
- Low power TTL compatibility


## Applications

- AND-OR select gating
- Shift-right/shift-left registers
- True/complement selection
- AND/OR/EXCLUSIVE-OR selection


## Connection Diagram

Dual-In-Line and Flat Package


Schematic Diagram


Schematic diagram for 1 of 4 identical stages

## Absolute Maximum Ratings

(Notes 1 and 2)
$V_{\text {DD }}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
PD Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
-0.5 to +18 V
-0.5 to $V_{D D}+0.5 \mathrm{~V}$ $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW $300^{\circ} \mathrm{C}$

Recommended Operating Conditions
(Note 2)
$V_{D D}$ Supply Voltage
3 to 15 V
$V_{\text {IN }}$ Input $V$ oltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4019BM
CD4019BC

## DC Electrical Characteristics CD4019вм (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.25 |  | 0.03 | 0.25 |  | 7.5 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.5 |  | 0.05 | 0.5 |  | 15 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 1.0 |  | 0.07 | 1.0 |  | 30 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\mathrm{IIO}_{0}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\left\|\mathrm{IO}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| $V_{\text {IL }}$ | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2 | 1.5 |  | 1.5 | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6 | 4.0 |  | 4.0 | v |
| $\mathrm{V}_{1} \mathrm{H}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 3 |  | 3.5 |  | v |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 6 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 9 |  | 11.0 |  | v |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=0.4 \mathrm{~V}$ | 0.64 | , | 0.51 | 1 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.5 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 10 |  | 2.4 |  | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.25 |  | -0.2 | -0.4 |  | -0.14 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -0.62 |  | -0.5 | -1.0 |  | -0.35 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -1.8 |  | -1.5 | -3.0 |  | -1.1 |  | mA |
| IN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.10 |  | $-10^{-5}$ | -0.10 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.10 |  | $10^{-5}$ | 0.10 |  | 1.0 | $\mu \mathrm{A}$ |

## DC Electrical Characteristics CD4019BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 1 |  | 0.03 | 1 |  | 7.5 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 2 |  | 0.05 | 2 |  | 15 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 4 | . | 0.07 | 4 |  | 30 | $\mu \mathrm{A}$ |
| $\mathrm{VOL}_{\text {OL }}$ | Low Level Output Voltage | $\left\|\mathrm{IO}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $\|1 \mathrm{O}\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| $V_{\text {IL }}$ | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \quad \mathrm{~V}_{0}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2 : | 1.5 |  | 1.5 | v |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6 | 4.0 |  | 4.0 | $v$ |
| $V_{\text {IH }}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1 \mathrm{~V} \text { or } 9 \mathrm{~V}$ | 7.0 |  | 7.0 | 6 |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 9 |  | 11.0 |  | V |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 1 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.5 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 10 |  | 2.4 |  | mA |
| ${ }^{\mathrm{O}} \mathrm{H}$ | High Level Output Current | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.2 |  | -0.16 | -0.4 |  | -0.12 |  | mA |
|  |  | $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -0.5 |  | -0.4 | -1.0 |  | -0.3 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -1.4 |  | -1.2 | -3.0 |  | -1.0 |  | mA |
| In | Input Current | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.30 |  | $-10^{-5}$ | -0.30 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1} \mathrm{~N}=15 \mathrm{~V}$ |  | 0.30 |  | $10^{-5}$ | 0.30 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}$, unless otherwise specified.

| PARAMETER |  | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL, TPLH | Propagation Delay Input to Output | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 300 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 120 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 45 | 100 | ns |
| tTHL | High-to-Low Level <br> Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| tTLH | Low-to-High Level Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 150 | 300 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 70 | 140 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 50 | 100 | ns |
| CIN | Input Capacitance | All $A$ and $B$ Inputs |  | 5 | 7.5 | pF |
|  |  | $K_{A}$ and $K_{B}$ Inputs, (Note 3) |  | 10 | 15 | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: Capacitance is guaranteed by periodic testing.

## CD4020BM/CD4020BC 14-Stage Ripple Carry Binary Counters CD4040BM/CD4040BC 12-Stage Ripple Carry Binary Counters CD4060BM/CD4060BC 14-Stage Ripple Carry Binary Counters

## General Description

The CD4020BM/CD4020BC, CD4060BM/CD4060BC are 14 -stage ripple carry binary counters, and the CD4040BM/ CD4040BC is a 12 -stage ripple carry binary counter. The counters are advanced one count on the negative transition of each clock pulse. The counters are reset to the zero state by a logical " 1 " at the reset input independent of clock.

## Features

- Wide supply voltage range
- High noise immunity
$0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
fan out of 2 driving 74L or 1 driving 74LS
8 MHz typ. at $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$
- Medium speed operation
- Schmitt trigger clock input


## Connection Diagrams

TOP VIEW



Absolute Maximum Ratings (Notes 1 and 2)
$V_{D D}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{S}} \quad$ Storage Temperature Range
$P_{D} \quad$ Package Dissipation
$T_{\mathrm{L}} \quad$ Lead Temperature (soldering, 10 seconds)
-0.5 V to +18 V
-0.5 V to $\mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW
$300^{\circ} \mathrm{C}$

## Recommended Operating Conditions

$V_{\text {DD }}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD40XXBM CD40XXBC
+3 V to +15 V
$O V$ to $V_{D D}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## DC Electrical Characteristics CD40xXBM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| $1{ }^{\text {ID }}$ | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 5 |  |  | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  |  | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  |  | 20 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D O}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level Input Voltage | $\mathrm{V}_{\text {DD }}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4 | 3.0 |  | 3.0 | V |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6 | 4.0 |  | 4.0 | V |
| $V_{I H}$ | High Level Input Voltage | $\mathrm{V}_{\text {DD }}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 3 |  | 3.5 |  | $V$ |
|  |  | $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 6 |  | 7.0 |  | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 9 |  | 11.0 |  | $V$ |
| IOL | Low Level Output Current (See Note 3) | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current (See Note 3) | $\mathrm{V}_{\text {DD }}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| $I_{\text {IN }}$ | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.10 |  | $-10^{.5}$ | -0.10 |  | $-1.0$ | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.10 |  | $10^{-5}$ | 0.10 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $V_{S S}=O V$ unless otherwise specified.
Note 3: Data does not apply to oscillator points $\phi_{0}$ and $\bar{\phi}_{0}$ of CD4060BM/CD4060BC.

DC Electrical Characteristics 40×XBC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| $I_{D D}$ | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 20 |  |  | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  |  | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  |  | 80 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {OL }}$ | Low Level Output Voltage | $V_{\text {DD }}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D O}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{O}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4 | 3.0 |  | 3.0 | V |
|  |  | $\mathrm{V}_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6 | 4.0 |  | 4.0 | V |
| $V_{\text {IH }}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  |  |  | 3 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V}$ | 7.0 |  | 7.0 | 6 |  | 7.0 |  | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 9 |  | 11.0 |  | V |
| IOL | Low Level Output Current (See Note 3) | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | $\mathrm{mA}$ |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| $\mathrm{I}_{\mathrm{OH}}$ | High Level Output Current (See Note 3) | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -3.6 |  | -3.6 | -8.8 |  | -2.4 |  | mA |
| $I_{\text {IN }}$ | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ | . | -0.30 |  | $-10^{-5}$ | -0.30 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.30 |  | $10^{-5}$ | 0.30 |  | 1.0 | $\mu \mathrm{A}$ |

## AC Electrical Characteristics cD4020вм/СD4020вс, СD4040BM/CD4040BC

$T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, R_{L}=200 \mathrm{k}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise noted.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {PHL } 1}, \mathrm{t}_{\text {PLH } 1}$ | Propagation Delay Time to $\mathrm{Q}_{1}$ | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 250 \\ & 100 \\ & 75 \end{aligned}$ | $\begin{aligned} & 550 \\ & 210 \\ & 150 \end{aligned}$ | ns <br> ns ns |
| $\mathrm{t}_{\text {PHL }}, \mathrm{t}_{\text {PLH }}$ | Interstage Propagation Delay Time from $Q_{n}$ to $Q_{n+1}$ | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 150 \\ & 60 \\ & 45 \end{aligned}$ | $\begin{aligned} & 330 \\ & 125 \\ & 90 \end{aligned}$ | ns ns ns |
| $\mathrm{t}_{\text {THL }}, \mathrm{t}_{\text {TLH }}$ | Transition Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{C D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 50 \\ & 40 \end{aligned}$ | $\begin{aligned} & 200 \\ & 100 \\ & 80 \end{aligned}$ | ns <br> ns ns |
| $t_{W L}, t_{W H}$ | Minimum Clock Pulse Width | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 125 \\ & 50 \\ & 40 \end{aligned}$ | $\begin{aligned} & 335 \\ & 125 \\ & 100 \end{aligned}$ | ns <br> ns <br> ns |
| $\mathrm{trCL}, \mathrm{t}_{\mathrm{fCL}}$ | Maximum Clock Rise and Fall Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  |  | no limit no limit no limit | ns <br> ns <br> ns |
| ${ }^{\text {c }}$ CL | Maximum Clock Frequency | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 4 \\ & 5 \end{aligned}$ | $\begin{aligned} & 4 \\ & 10 \\ & 12 \end{aligned}$ |  | MHz <br> MHz <br> MHz |
| $\mathrm{t}_{\text {PHL(R) }}$ | Reset Propagation Delay | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 200 \\ & 100 \\ & 80 \end{aligned}$ | $\begin{aligned} & 450 \\ & 210 \\ & 170 \end{aligned}$ | ns <br> ns ns |
| $t_{W H(R)}$ | Minimum Reset Pulse Width | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 200 \\ & 100 \\ & 80 \end{aligned}$ | $\begin{aligned} & 450 \\ & 210 \\ & 170 \end{aligned}$ | ns <br> ns ns |
| $\mathrm{C}_{\text {in }}$ | Average Input Capacitance | Any Input (Note 1) |  | 5 | 7.5 | pF |
| $\mathrm{C}_{\mathrm{pd}}$ | Power Dissipation Capacitance | (Note 2) |  | 50 |  | pF |

Note 1: Capacitance guaranteed by periodic testing.
Note 2: Cpd determines the no-load etc.

AC Electrical Characteristics CD4060BM/CD4060BC $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise noted

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {PHL4 }}, \mathrm{t}_{\text {PLH4 }}$ | Propagation Delay Time to $\mathrm{Q}_{4}$ | $V_{D D}=5 \mathrm{~V}$ |  | 550 | 1300 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 250 | 525 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 200 | 400 | ns |
| $t_{\text {PHL }}, \mathrm{t}_{\text {PLH }}$ | Interstage Propagation Delay Time from $Q_{n}$ to $Q_{n+1}$ | $V_{D D}=5 \mathrm{~V}$ |  | 150 | 330 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 60 | 125 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 45 | 90 | ns |
| $\mathrm{t}_{\text {THL }}, \mathrm{t}_{\text {TLH }}$ | Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| $t_{\text {WL }}, t_{\text {WH }}$ | Minimum Clock Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 170 | 500 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 65 | 170 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 50 | 125 | ns |
| $\mathrm{trCL}, \mathrm{t}_{\mathrm{fCL}}$ | Maximum Clock Rise and Fall Time | $V_{D D}=5 \mathrm{~V}$ |  |  | no limit | ns |
|  |  | V $V_{D D}=10 \mathrm{~V}$ |  |  | no limit | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  |  | no limit | ns |
| $\mathrm{f}_{\mathrm{CL}}$ | Maximum Clock Frequency | $V_{D D}=5 \mathrm{~V}$ |  |  |  | MHz |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 3 | 8 |  | MHz |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 4 | 10 |  | MHz |
| $t_{\text {PHL(R) }}$ | Reset Propagation Delay | $V_{D D}=5 \mathrm{~V}$ |  | 200 | 450 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 100 | 210 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 | 170 | ns |
| $t_{\text {WH(R) }}$ | Minimum Reset Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 200 | 450 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 100 | 210 | ns |
|  |  | $\mathrm{V}_{\text {DD }}=15 \mathrm{~V}$ |  | 80 | 170 | ns |
| $\mathrm{C}_{\text {in }}$ | Average Input Capacitance | Any Input (Note 1) |  | 5 | 7.5 | pF |
| $\mathrm{C}_{\mathrm{pd}}$ | Power Dissipation Capacitance | (Note 2) |  | 50 |  | pF |

Note 1: Capacitance guaranteed by periodic testing.
Note 2: Cpd determines the no-load etc.

## CD4060B Typical Oscillator Connections



RC Oscillator


Crystal Oscillator

Schematic Diagrams



## CD4021BM/CD4021BC 8-Stage Static Shift Register

## General Description

The CD4021BM/CD4021BC is an 8-stage parallel input/ serial output shift register. A parallel/serial control input enables individual JAM inputs to each of 8 stages. Q output are available from the sixth, seventh, and eighth stages. All outputs have equal source and sink current capabilities and conform to standard "B" series output drive.

When the parallel/serial control input is in the logical " 0 " state, data is serially shifted into the register synchronously with the positive transition of the clock. When the parallel/serial control is in the logical " 1 " state, data is jammed into each stage of the register asynchronously with the clock.

All inputs are protected against static discharge with diodes to $V_{D D}$ and $V_{S S}$.

## Features

- Wide supply voltage range: 3.0 V to 15 V
- High noise immunity: $0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
- Low power TTL compatibility fan out of 2 driving 74 L or 1 driving 74LS
- $5 \mathrm{~V}-10 \mathrm{~V}-15 \mathrm{~V}$ parametric ratings
- Symmetrical output characteristics
- Maximum input leakage $1 \mu \mathrm{~A}$ at 15 V over full temperature range


## Connection Diagram

Dual-In-Line Package


| $\mathrm{CL}^{*}$ | Serial <br> Input | Parallell <br> Serial <br> Control | PI1 | PIn | $Q_{1}$ <br> (Internal) | $\mathbf{Q}_{\mathbf{n}}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| X | X | 1 | 0 | 0 | 0 | 0 |
| X | X | 1 | 0 | 1 | 0 | 1 |
| X | X | 1 | 1 | 0 | 1 | 0 |
| X | X | 1 | 1 | 1 | 1 | 1 |
| X | 0 | 0 | X | X | 0 | $\mathrm{Q}_{n \cdot 1}$ |
| X | X | 0 | X | X | 1 | $\mathrm{Q}_{n-1}$ |

*Level change $X=$ Don't care case

TOP VIEW
Logic Diagram

$V_{\text {DD }}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
${ }^{\text {TS }}$ Storage Temperature Range
PD Package Dissipation
TL Lead Temperature (Soldering, 10 seconds)
-0.5 to +18 V
-0.5 to $V_{D D}+0.5 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW $300^{\circ} \mathrm{C}$

| $V_{D D}$ Supply Voltage | 3 to 15 V |
| :--- | ---: |
| $V_{\text {IN }}$ Input Voltage | 0 to $V_{D D}$ |
| $T_{A}$ Operating Temperature Range |  |
| CD4021BM | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD4021BC | $40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

DC Electrical Characteristics (Note 2) - CD4021BM

| Parameter |  | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Typ | Max | Min | Max |  |
| $I_{D D}$ | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 5 |  | 0.1 | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  | 0.2 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  | 0.3 | 20 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $\left.V_{D D}=10 \mathrm{~V}\right\}\left\|\left.\right\|_{0}\right\|<1 \mu \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ ( |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $\left.V_{D D}=10 \mathrm{~V}\right\}\left\|H_{0}\right\|<1 \mu \mathrm{~A}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL | Low Level Input Voltage | $\mathrm{V}_{\text {DD }}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High Level Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 3 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 6 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 9 |  | 11.0 |  | V |
| $\mathrm{IOL}^{\text {L }}$ | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.2 |  | 0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8 |  | 2.4 |  | mA |
| $\mathrm{I}_{\mathrm{OH}}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.2 |  | -0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8 |  | -2.4 |  | mA |
| $\mathrm{I}_{\mathrm{IN}}$ | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.10 |  | $-10^{-5}$ | -0.10 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.10 |  | $10^{-5}$ | 0.10 |  | 1.0 | $\mu \mathrm{A}$ |

## DC Electrical Characteristics (Note 2) - CD4021BC

| Parameter |  | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Typ | Max | Min | Max |  |
| '00 | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 20 |  | 0.1 | 20. |  | 150 | $\mu \mathrm{A}$ |
|  |  |  |  | 40 |  | . 0.2 | 40 |  | 300 | ${ }_{\mu} \mathrm{A}$ |
|  |  |  |  | 80 |  | 0.3 | 80 |  | 600 | ${ }_{\mu} \mathrm{A}$ |
| $\mathrm{V}_{\text {OL }}$ | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $\mathrm{V}_{\text {DD }}=10 \mathrm{~V} \quad \mid \mathrm{I}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | $v$ |
|  |  | $V_{\text {DD }}=10 \mathrm{~V} \quad\left\|\mathrm{I}_{0}\right\|<1 \mu \mathrm{~A}$ | 9.95 |  | 9.95, | 10 |  | 9.95 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ ( | 14.95 |  | 14.95 | 15 |  | 14.95 |  | $v$ |
| $\mathrm{V}_{\text {IL }}$ | Low Level Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2 | 1.5 |  | 1.5 | $v$ |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4 | 3.0 |  | 3.0 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6 | 4.0 |  | 4.0 | $v$ |
| $\mathrm{V}_{\mathrm{IH}}$ | High Level Input Voitage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 3 |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 6 |  | 7.0 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 9 |  | 11.0 |  | v |
| 1 OL | Low Level Output Current | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.2 |  | 0.90 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8 |  | 2.4 |  | mA |
| $\mathrm{I}^{\mathrm{OH}}$ | High Level Output Current | $\mathrm{V}_{\text {D }}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{0}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.2 |  | -0.90 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8 |  | -2.4 |  | mA |
| In | Input Current | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}$, input $t_{r}, t_{f}=20 \mathrm{~ns}, C_{L}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k} \Omega$

|  | Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {PLH }}, \mathrm{t}_{\text {PHL }}$ | Propagation Delay Time | $V_{D D}=5 \mathrm{~V}$ |  | 240 | 350 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 100 | 175 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 70 | 140 | ns |
| ${ }^{\text {THLL }}$, $\mathrm{t}_{\text {TLH }}$ | Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| $\mathrm{f}_{\mathrm{CL}}$ | Maximum Clock Input Frequency | $V_{D D}=5 \mathrm{~V}$ | 2.5 | 3.5 |  | MHz |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 5 | 10 |  | MHz |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 8 | 16 |  | MHz |
| $t_{\text {w }}$ | Minimum Clock Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| $\mathrm{tr}_{\mathrm{r}} \mathrm{CL}, \mathrm{t}_{\mathrm{f}} \mathrm{CL}$ | Clock Rise and Fall Time (Note 3) | $\mathrm{V}_{\text {DD }}=5 \mathrm{~V}$ | $\cdot$ |  | 15 | $\mu \mathrm{S}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  |  | 15 | $\mu \mathrm{S}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  |  | 15 | $\mu \mathrm{S}$ |
| $\mathrm{t}_{\text {s }}$ | Minimum Set-up Time |  |  |  |  |  |
|  | Serial Input | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 60 | 120 | ns |
|  | $\mathrm{t}_{\mathrm{H}} \geq 200 \mathrm{~ns}$ | $V_{D D}=10 \mathrm{~V}$ |  | 40 | 80 | ns |
|  | (Ref. to CL) | $V_{D D}=15 \mathrm{~V}$ |  | 30 | 60 | ns |
|  | Parallel Inputs | $V_{D D}=5 \mathrm{~V}$ |  | 25 | 50 | ns |
|  | $t_{H} \geq 200 \mathrm{~ns}$ | $V_{D D}=10 \mathrm{~V}$ |  | 15 | 30 | ns |
|  | (Ref. to P/S) | $V_{D D}=15 \mathrm{~V}$ |  | 10 | 20 | ns |
| $t_{H}$ | Minimum Hold Time Serial In, Parallel In, $\mathrm{t}_{\mathrm{s}} \geq 400 \mathrm{~ns}$ Parallel/Serial Control | $V_{D D}=5 \mathrm{~V}$ |  |  | 0 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  |  | 10 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  |  | 15 | ns |
| $t_{\text {WH }}$ | Minimum P/S Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 150 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 75 | 125 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 50 | 100 | ns |
| $t_{\text {REM }}$ | Minimum P/S Removal Time (Ref. to CL) | $\mathrm{V}_{\text {DD }}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| $C_{1}$ | Average Input Capacitance | Any Input |  | 5 | 7.5 | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance (Note 4) |  |  | 100 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: If more than one unit is cascaded $\mathrm{t}_{\mathrm{r}} \mathrm{CL}$ should be made less than or equal to the fixed propagation delay of the output of the driving stage for the estimated capacitive load.
Note 4: CPD determines the no load AC power consumption of any CMOS device. For complete explanation, see 54C/74C family characteristics application note AN-90.

## Typical Performance Characteristics





## CD4023M/CD4023C Triple 3-Input NAND Gate CD4025M/CD4025C Triple 3-Input NOR Gate

## General Description

These triple gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N - and P-channel enhancement mode transistors. All inputs are protected against static discharge with diodes to $V_{D D}$ and $V_{S S}$.

## Features

- Wide supply voltage range
3.0 V to 15 V
- High noise immunity
$0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
- 5-10 V parametric ratings
- Low Power


## Connection Diagrams



CD4023M/CD4023C
TOP VIEW


CD4025M/CD4025C
TOP VIEW

## Absolute Maximum Ratings (Note 1)

Voltage at Any Pin
Operating Temperature Range CD4023M, CD4025M CD4023C, CD4025C
$V_{S S}-$ to $V_{D D}+0.3 V$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

Storage Temperature Range Package Dissipation Operating $V_{D D}$ Range Lead Temperature (Soldering, 10 seconds) $300^{\circ} \mathrm{C}$

|  | Parameter | Conditions | Limits |  |  |  |  |  |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |
|  |  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| $\mathrm{I}_{\mathrm{L}}$ | Quiescent Device Current | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 0.05 \\ 0.1 \end{gathered}$ |  | $\begin{aligned} & 0.001 \\ & 0.001 \end{aligned}$ | $\begin{gathered} 0.05 \\ 0.1 \end{gathered}$ |  | $\begin{aligned} & 3.0 \\ & 6.0 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |
| $\mathrm{P}_{\mathrm{D}}$ | Quiescent Device Dissipation/Package | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 0.25 \\ 1.0 \end{gathered}$ |  | $\begin{gathered} 0.005 \\ 0.01 \end{gathered}$ | $\begin{gathered} 0.25 \\ 1.0 \end{gathered}$ |  | $\begin{aligned} & 15 \\ & 60 \end{aligned}$ | $\mu \mathrm{W}$ $\mu \mathrm{W}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Output Voltage Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{1}=V_{D D}, I_{O}=0 \mathrm{~A} \\ & V_{D D}=10 \mathrm{~V}, V_{1}=V_{D D}, l_{O}=0 \mathrm{~A} \end{aligned}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ |  | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Voltage High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{I}=V_{S S}, I_{O}=0 \mathrm{~A} \\ & V_{D D}=10 \mathrm{~V}, V_{1}=V_{S S}, l_{O}=0 \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ |  | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ | 5.0 10 |  | $\begin{aligned} & 4.95 \\ & 9.95 \end{aligned}$ |  | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\mathrm{NL}}$ | Noise Immunity (All Inputs) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=3.6 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=7.2 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \end{aligned}$ | $\begin{gathered} 2.25 \\ 4.5 \end{gathered}$ |  | $\begin{aligned} & 1.4 \\ & 2.9 \end{aligned}$ |  | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\mathrm{NH}}$ | Noise Immunity (All Inputs) | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=0.95 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=2.9 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 1.4 \\ & 2.9 \end{aligned}$ |  | 1.5 3.0 | 2.25 4.5 |  | 1.5 3.0 |  | $\begin{aligned} & V \\ & V \end{aligned}$ |
| $I_{D} N$ | Output Drive Current N-Channel (4025) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}, V_{1}=V_{D D} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}, V_{1}=V_{D D} \end{aligned}$ | $\begin{aligned} & 0.5 \\ & 1.1 \end{aligned}$ |  | $\begin{gathered} 0.40 \\ 0.9 \end{gathered}$ | $\begin{aligned} & 1.0 \\ & 2.5 \end{aligned}$ |  | $\begin{aligned} & 0.28 \\ & 0.65 \end{aligned}$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $I_{D} P$ | Output Drive Current P-Channel (4025) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=2.5 \mathrm{~V}, V_{1}=V_{S S} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}, V_{1}=V_{S S} \end{aligned}$ | $\begin{aligned} & -0.62 \\ & -0.62 \end{aligned}$ |  | -0.5 -0.5 | -2.0 -1.0 |  | -0.35 -0.35 |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $\mathrm{I}_{\mathrm{D}} \mathrm{N}$ | Output Drive Current N-Channel (4023) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}, V_{1}=V_{D D} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}, V_{1}=V_{D D} \end{aligned}$ | $\begin{aligned} & 0.31 \\ & 0.63 \end{aligned}$ |  | $\begin{gathered} 0.25 \\ 0.5 \end{gathered}$ | $\begin{aligned} & 0.5 \\ & 0.6 \end{aligned}$ |  | $\begin{gathered} 0.175 \\ 0.35 \end{gathered}$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $I_{D} P$ | Output Drive Current P-Channel (4023) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{0}=2.5 \mathrm{~V}, V_{1}=V_{S S} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}, V_{1}=V_{S S} \end{aligned}$ | $\begin{aligned} & -0.31 \\ & -0.75 \end{aligned}$ |  | $\left\lvert\, \begin{aligned} & -0.25 \\ & -0.6 \end{aligned}\right.$ | $\begin{aligned} & -0.5 \\ & -1.2 \end{aligned}$ |  | $\left\|\begin{array}{c} -0.175 \\ -0.4 \end{array}\right\|$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| 1 | Input Current |  |  |  |  | 10 |  |  |  | pA |


| Parameter |  | Conditions | Limits |  |  |  |  |  |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $-40^{\circ} \mathrm{C}$ | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| $I_{L}$ | Quiescent Device Current |  | $V_{D D}=5.0 \mathrm{~V}$ |  | 0.5 |  | 0.005 | 0.5 |  | 15 | $\mu \mathrm{A}$ |
|  |  |  | $V_{D D}=10 \mathrm{~V}$ |  | 5.0 |  | 0.005 | 5.0 |  | 30 | $\mu \mathrm{A}$ |
| $\mathrm{P}_{\mathrm{D}}$ | Quiescent Device Dissipation/Package | $\mathrm{V}_{\text {DD }}=5.0 \mathrm{~V}$ |  | 2.5 |  | 0.025 | 2.5 |  | 75 | $\mu \mathrm{W}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 |  | 0.05 | 50 |  | 300 | $\mu \mathrm{W}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Output Voltage Low Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{1}=V_{D D}, 0=0 \mathrm{~A}$ |  | 0.01 |  | 0 | 0.01 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{1}=V_{D D}, l_{0}=0 \mathrm{~A}$ |  | 0.01 |  | 0 | 0.01 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Voltage High Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{1}=V_{S S}, l_{0}=0 \mathrm{~A}$ | 4.99 |  | 4.99 | 5.0 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{S S}, \mathrm{I}_{0}=0 \mathrm{~A}$ | 9.99 |  | 9.99 | 10 |  | 9.95 |  | V |
| $\begin{aligned} & I_{I} \\ & V_{N L} \end{aligned}$ | Input Current |  |  |  |  | 10 |  |  |  | pA |
|  | Noise Immunity (All Inputs) | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=3.6 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A}$ | 1.5 |  | 1.5 | 2.25 |  | 1.4 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=7.2 \mathrm{~V}, \mathrm{I}_{0}=0 \mathrm{~A}$ | 3.0 |  | 3.0 | 4.5 |  | 2.9 |  | V |
| $\mathrm{V}_{\mathrm{NH}}$ | Noise Immunity (All Inputs) | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=0.95 \mathrm{~V}, \mathrm{I}_{0}=0 \mathrm{~A}$ | 1.4 |  | 1.5 | 2.25 |  | 1.5 |  | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=2.9 \mathrm{~V}, \mathrm{I}_{0}=0 \mathrm{~A}$ | 2.9 |  | 3.0 | 4.5 |  | 3.0 |  | V |
| $I_{D} \mathrm{~N}$ | Output Drive Current N-Channel (4025) | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{\mathrm{DD}}$ | 0.35 |  | 0.3 | 1.0 |  | 0.24 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}, V_{1}=V_{D D}$ | 0.72 |  | 0.6 | 2.5 |  | 0.48 |  | mA |
| $I_{D} P$ | Output Drive Current <br> P-Channel (4025) | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=2.5 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{S S}$ | -0.35 |  | -0.3 | -2.0 |  | -0.24 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{S S}$ | -0.3 |  | -0.25 | -1.0 |  | -0.2 |  | mA |
| $I_{0} \mathrm{~N}$ | Output Drive Current N-Channel (4023) | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{\mathrm{DD}}$ | 0.145 |  | 0.12 | 0.5 |  | 0.095 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{\mathrm{DD}}$ | 0.3 |  | 0.25 | 0.6 |  | 0.2 |  | mA |
| $I_{D} P$ | Output Drive Current P-Channel (4023) | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=2.5 \mathrm{~V}, \mathrm{~V}_{1}=\mathrm{V}_{S S}$ | -0.145 |  | -0.12 | -0.5 |  | -0.095 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}, V_{1}=V_{S S}$ | -0.35 |  | -0.3 | -1.2 |  | -0.24 |  | mA |
| 1 | Input Current |  |  |  |  | 10 |  |  |  | pA |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$. Typical temperature coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CD4025M |  |  |  |  |  |  |
| $\mathrm{t}_{\text {PHL }}$ | Propagation Delay Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | 35 25 | $\begin{aligned} & 50 \\ & 40 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {PLH }}$ | Propagation Delay Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 35 \\ & 25 \end{aligned}$ | $\begin{aligned} & 40 \\ & 70 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| ${ }^{\text {t }}$ HL | Transition Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 65 \\ & 35 \end{aligned}$ | $\begin{aligned} & 125 \\ & 70 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| ${ }^{\text {trin }}$ | Transition Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 65 \\ & 35 \end{aligned}$ | $\begin{aligned} & 175 \\ & 75 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{C}_{1}$ | Input Capacitance | Any Input |  | 5.0 |  | pF |
| CD4025C |  |  |  |  |  |  |
| $\mathrm{t}_{\text {PHL }}$ | Propagation Delay Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 35 \\ & 25 \end{aligned}$ | $\begin{aligned} & 80 \\ & 55 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{t}_{\text {PLH }}$ | Propagation Delay Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 35 \\ & 25 \end{aligned}$ | $\begin{aligned} & 120 \\ & 65 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| ${ }_{\text {t }}^{\text {THL }}$ | Transition Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 65 \\ & 35 \end{aligned}$ | $\begin{aligned} & 200 \\ & 115 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \text { ns } \end{aligned}$ |
|  | Transition Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | 65 35 | $\begin{aligned} & 300 \\ & 125 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| ${ }^{\prime} \mathrm{C}_{1}$ | Input Capacitance | Any Input |  | 5.0 |  | pF |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$. Typical temperature coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CD4023M |  |  |  |  |  |  |
| $\mathrm{t}_{\text {PHL }}$ | Propagation Delay Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{aligned} & 75 \\ & 40 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {PLH }}$ | Propagation Delay Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{aligned} & 75 \\ & 40 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {THL }}$ | Transition Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 75 \\ & 50 \end{aligned}$ | $\begin{aligned} & 125 \\ & 75 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| ${ }_{\text {tith }}$ | Transition Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 75 \\ & 40 \end{aligned}$ | $\begin{aligned} & 100 \\ & 60 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{C}_{1}$ | Input Capacitance | Any Input |  | 5.0 |  | pF |
| CD4023C |  |  |  |  |  |  |
| $\mathrm{t}_{\text {PHL }}$ | Propagation Delay Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{aligned} & 100 \\ & 50 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {PLH }}$ | Propagation Delay Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{aligned} & 100 \\ & 50 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {THL }}$ | Transition Time High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 75 \\ & 50 \end{aligned}$ | $\begin{aligned} & 150 \\ & 100 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
|  | Transition Time Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 75 \\ & 40 \end{aligned}$ | $\begin{aligned} & 125 \\ & 75 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{C}_{1}$ | Input Capacitance | Any Input |  | 5.0 |  | pF |

## CD4023BM/CD4023BC Buffered Triple 3-Input NAND Gate CD4025BM/CD4025BC Buffered Triple 3-Input NOR Gate

## General Description

These triple gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N - and P-channel enhancement mode transistors. They have equal source and sink current capabilities and conform to standard B series output drive. The devices also have buffered outputs which improve transfer characteristics by providing very high gain. All inputs are protected against static discharge with diodes to $V_{D D}$ and $V_{S S}$.

Features

- Wide supply voltage range
3.0 V to 15 V
- High noise immunity
- Low power TTL compatibility
$0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
fan out of 2 driving 74L or 1 driving 74LS
- $5 \mathrm{~V}-10 \mathrm{~V}-15 \mathrm{~V}$ parametric ratings
- Symmetrical output characteristics
- Maximum input leakage $1 \mu \mathrm{~A}$ at 15 V over full temperature range


## Connection Diagrams



# Absolute Maximum Ratings (Notes 1 and 2 ) 

$V_{D D}$ DC Supply Voltage $\quad-0.5 \mathrm{~V}_{\mathrm{DC}}$ to $+18 \mathrm{~V}_{\mathrm{DC}}$
$V_{I N}$ Input Voltage $\quad-0.5 V_{D C}$ to $V_{D D}+0.5 V_{D C}$
$\mathrm{T}_{\mathrm{S}} \quad$ Storage Temperature Range $\quad-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
$P_{D}$ Packagé Dissipation 500 mW
$\mathrm{T}_{\mathrm{L}} \quad$ Lead Temperature (soldering, 10 seconds) $300^{\circ} \mathrm{C}$

| $V_{D D}$ DC Supply Voltage | $+5 V_{D C}$ to $+15 V_{D C}$ |
| :--- | ---: |
| $V_{\text {IN }}$ Input Voltage | $0 V_{D C}$ to $V_{D D} V_{D C}$ |
| $T_{A}$ Operating Temperature Range |  |
| $C D 4023 B M, C D 4025 B M$ | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| $C D 4023 B C, C D 4025 B C$ | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

VD DC Supply Voltage
$5 V_{D C}$ to $+15 V_{D C}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

DC Electrical Characteristics - CD4023BM, CD4025BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.25 |  | 0.004 | 0.25 |  | 7.5 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.5 |  | 0.005 | 0.5 |  | 15 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 1.0 |  | 0.006 | 1.0 |  | 30 | $\mu \mathrm{A}$ |
| V OL | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| $V_{\text {IL }}$ | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=4.5 \mathrm{~V}$ |  | 1.5 |  | 2 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.0 \mathrm{~V},\left\|\left.\right\|_{0}\right\|<1 \mu \mathrm{~A}$ |  | 3.0 |  | 4 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=13.5 \mathrm{~V}$ ) |  | 4.0 |  | 6 | 4.0 |  | 4.0 | V |
| $V_{1 H}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ | 3.5 |  | 3.5 | 3 |  | 3.5 |  | V |
|  |  | $\left.V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V}\right\}\left\|I_{O}\right\|<1 \mu \mathrm{~A}$ | 7.0 |  | 7.0 | 6 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ | 11.0 |  | 11.0 | 9 |  | 11.0 |  | V |
| $\mathrm{I}_{\mathrm{OL}}$ | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.2 |  | 0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8 |  | 2.4 |  | mA |
| $\mathrm{I}^{\mathrm{OH}}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.2 |  | -0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8 |  | -2.4 |  | mA |
| 1 IN | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.10 |  | $-10^{-5}$ | -0.10 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.10 |  | $10^{-5}$ | 0.10 |  | 1.0 | $\mu \mathrm{A}$ |

## schematic diagram




DC Electrical Characteristics CD4023BC, CD4025BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  |  |  | 0.004 |  |  | 7.5 | $\mu \mathrm{A}$ |
|  |  |  |  |  |  | 0.005 |  |  | 15 | $\mu \mathrm{A}$ |
|  |  |  |  |  |  | 0.006 |  |  | 30 | $\mu \mathrm{A}$ |
| VoL | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| VIL | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=4.5 \mathrm{~V}$ |  | 1.5 |  | 2 | 1.5 |  | 1.5 | V |
|  |  | $\left.V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.0 \mathrm{~V}\right\}\left\|I_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ |  | 3.0 |  | 4 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=13.5 \mathrm{~V}$ |  | 4.0 |  | 6 | 4.0 |  | 4.0 | v |
| $V_{\text {IH }}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, ~ V_{0}=0.5 \mathrm{~V}$ | 3.5 |  | 3.5 | 3 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$, $\\| \mathrm{I}_{\mathrm{O}} \mid<1 \mu \mathrm{~A}$ | 7.0 |  | 7.0 | 6 |  | 7.0 |  | v |
|  |  | $\mathrm{V}_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ | 11.0 |  | 11.0 | 9 |  | 11.0 |  | $v$ |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $\mathrm{V}_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.2 |  | 0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8 |  | 2.4 |  | mA |
| $\mathrm{IOH}^{\text {O }}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.2 |  | -0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8 |  | -2.4 |  | mA |
| 1 IN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $\mathrm{V}_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Cháracteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

## schematic diagram



AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, R_{L}=200 \mathrm{k}$, unless otherwise specified.

| PARAMETER |  | CONDITIONS | $\begin{aligned} & \text { CD4023BC } \\ & \text { CD4023BM } \end{aligned}$ |  |  | $\begin{aligned} & \text { CD4025BC } \\ & \text { CD4025BM } \end{aligned}$ |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP | MAX | MIN | TYP | MAX |  |
| ${ }^{\text {tPHL }}$ | Propagation Delay, High to Low Level |  | $V_{D D}=5 \mathrm{~V}$ |  | 130 | 250 |  | 130 | 250 | ns |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}$ |  | 60 | 100 |  | 60 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 70 |  | 40 | 70 | ns |
| ${ }^{\text {tPLH }}$ | Propagation Delay, Low to High Level | $V_{D D}=5 \mathrm{~V}$ |  | 110 | 250 |  | 120 | 250 | ns |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}$ |  | 50 | 100 |  | 60 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 35 | 70 |  | 40 | 70 | ns |
| $\begin{aligned} & \mathrm{t}_{\mathrm{THL}} \\ & \mathrm{t}_{\mathrm{TLH}} \end{aligned}$ | Transition Time | $\mathrm{V}_{D D}=5 \mathrm{~V}$ |  | 90 | 200 |  | 90 | 200 | ns |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}$ |  | 50 | 100 |  | 50 | 100 | ns |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}$ |  | 40 | 80 |  | 40 | 80 | ns |
| $\mathrm{C}_{\text {IN }}$ | Average Input Capacitance (See Note 3) | Any Input |  | 5 | 7.5 |  | 5 | 7.5 | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacity (See Note 4) | Any Gate |  | 17 |  |  | 17 |  | pF |

Note 3: Capacitance is guaranteed by periodic testing.
Note 4: CPD determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family characteristics Application Note AN-90.

## CD4024BM/CD4024BC 7-Stage Ripple Carry Binary Counter

Features

- Wide supply voltage range
3.0 V to 15 V
$0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
fan out of 2 driving 74L or 1 driving 74LS

12 MHz (typ.)
input pulse rate $V_{D D}-V_{S S}=10 \mathrm{~V}$

- Fu'lly static operation

Connection Diagram


TOP VIEW

## Logic Diagram



## Schematic Diagram




Input Logic
Flip-flop logic (1 of 7 identical stages).

Absolute Maximum Ratings
(Notes 1 and 2)
$V_{D D}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{S}}$ Storage Temperature Range
$P_{D}$ Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)

Recommended Operating Conditions
(Note 2)
$V_{D D}$ de Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4024BM
CD4024BC

DC Electrical Characteristics CD4024BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 5 |  | 0.3 | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  | 0.5 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  | 0.7 | 20 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\mathrm{HO}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\text {D }}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\mid \mathrm{IIO}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | $v$ |
| VIL | Low Level Input Voltage | $\\|^{\prime} \mathrm{l} \mid<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2 | 1.5 |  | 1.5 | $v$ |
|  |  | $\mathrm{V}_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4 | 3.0 |  | 3.0 | $v$ |
|  |  | $\mathrm{V}_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6 | 4.0 |  | 4.0 | $v$ |
| $\mathrm{V}_{1}$ | High Level İnput Voltage | $\mid{ }^{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 3 |  | 3.5 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 6 |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 9 |  | 11.0 |  | V |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| 1 OH | High Level Qutput Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ |  | -0.10 |  | $-10^{-5}$ | -0.10 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.10 |  | $10^{-5}$ | 0.10 |  | 1.0 | $\mu \mathrm{A}$ |

DC Electrical Characteristics CD4024BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\mathrm{V}_{\text {DD }}=5 \mathrm{~V}$ |  | 20 |  | 0.3 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.5 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 60 |  | 0.7 | 80 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $1 \mathrm{l}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 |  |  | 0.05 | v |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\\|_{0} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |

DC Electrical Characteristics (Cont'd.) CD4024BC (Note 2)

|  | PARAMETER | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | TYP | max | MIN | MAX |  |
| $V_{\text {IL }}$ | Low Level Input Voltage | $\mathrm{H}_{0} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2 | 1.5 |  | 1.5 | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6 | 4.0 |  | 4.0 | V |
| $V_{\text {IH }}$ | High Level Input Voitage | $\left\\|{ }^{\prime}\right\\|^{\prime}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 3 |  | 3.5 |  | v |
|  |  | $\mathrm{V}_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 6 |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 9 |  | 11.0 |  | $v$ |
| 1 OL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| $\mathrm{IOH}^{\text {O }}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{0}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V} / \mathrm{V}_{0}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| In | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ |  | -0.30 |  | $-10^{-5}$ | -0.30 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V}$ |  |  |  | $10^{-5}$ | 0.30 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}, \mathrm{t}_{\mathrm{I}}$ and $\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$ unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL. tPLH | Propagation Delay Time (Note 3) | $V_{D D}=5 \mathrm{~V}$ |  | 185 | 350 | ns |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}$ |  | 85 | 125 | ns |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 70 | 100 | ns |
| ${ }^{\text {t }}$ THL, t TLH | Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| tWL, tWH | Minimum Input Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 75 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 | 110 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 35 | 90 | ns |
| $t_{\text {RCL }}, t_{\text {FCL }}$ | Input Rise and Fall Time | $V_{D D}=5 V$ |  |  | 15 | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  |  | 10 | $\mu s$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  |  | 8 | $\mu \mathrm{s}$ |
| ${ }^{\mathrm{f}} \mathrm{CL}$ | Maximum Input Pulse Frequency | $V_{D D}=5 \mathrm{~V}$ | 1.5 | 5 |  | MHz |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 4 | 12 |  | MHz |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 5 | 15 |  | MHz |
| tPHL | Reset Propagation Delay Time | $V_{D D}=5 \mathrm{~V}$ |  | 185 | 350 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 85 | 125 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 70 | 100 | ns |
| tWH | Reset Minimum Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 185 | 350 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 85 | 125 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 70 | 100 | ns |
| CIN | Input Capacitance (Note 4) | Any Input |  | 5 | 7.5 | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: To Q1 output.
Note 4: Capacitance is guaranteed by periodic testing.

## CD4027BM／CD4027BC Dual J－K Master／Slave Flip－Flop with Set and Reset

## General Description

These dual J－K flip－flops are monolithic complementary MOS（CMOS）integrated circuits constructed with N －and P－channel enhancement mode transistors．Each flip－flop has independent J，K，set，reset，and clock inputs and buffered $Q$ and＂$Q$＂outputs．These flip－flops are edge sensitive to the clock input and change state on the positive－going transition of the clock pulses．Set or reset is independent of the clock and is accomplished by a high level on the respective input．

All inputs are protected against damage due to static discharge by diode clamps to $V_{D D}$ and $V_{S S}$ ．

Features
－Wide supply voltage range
3.0 V to 15 V
－High noise immunity
－Low power TTL compatibility
－Low power
■ Medium speed operation
12 MHz （typ．） with 10 V supply

## Schematic Diagram



## Connection Diagram

Dual－In－Line and Flat Package


TOP VIEW

Absolute Maximum Ratings (Notes 1 and 2)
$V_{\text {DD }}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
$T_{S}$ Storage Temperature Range
PD Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
-0.5 to $+18 V_{D C}$
-0.5 to $V_{D D}+0.5 V_{D C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$300^{\circ} \mathrm{C}$

Recommended Operating Conditions
(Note 2)
VDD dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
TA Operating Temperature Range
CD4027BM
CD4027BC

3 to $15 V_{D C}$ 0 to $V_{D D} V_{D C}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

DC Electrical Characteristics CD4027BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\prime \prime} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| 100 | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 1 |  |  | 1 |  | 30 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 2 |  |  | 2 |  | 60 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 4 |  |  | 4 |  | 120 | $\mu \mathrm{A}$ |
| $\mathrm{v}_{\mathrm{OL}}$ | Low Level Output Voltage | $\\|_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\\|_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  |  | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | V |
| $V_{\text {IH }}$ | High Level Input Voltage | $V_{\text {DD }}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 |  |  | 7.0 |  | V |
| " |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | $v$ |
| 1 OL | Low Level Output Current | $V_{\text {DD }}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{1 N}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | $-1.0$ | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

## DC Electrical Characteristics (Cont'd.) CD4027BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 4 |  |  | 4 |  | 30 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 8 |  |  | 8 |  | 60 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 16 |  |  | 16 |  | 120 | $\mu \mathrm{A}$ |
| $\mathrm{v}_{\mathrm{OL}}$ | Low Level Output Voltage | $\left\\|_{0}\right\\|^{\prime}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | - V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| VOH | High Level Output Voltage | $\\|^{\prime} \mathrm{O} \mid<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V D D=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level Input Voltage | $V_{\text {DD }}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  |  | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{1 \mathrm{H}}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 |  |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | $\checkmark$ |
| 1 OL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{O}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |

## DC Electrical Characteristics CD4027BC (Note 2)

| PARAMETER |  | CONDITIONS | -40 ${ }^{\prime \prime}$ |  | 25 C |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | $-2.25$ |  | -09 |  | $m A$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -3.6 |  | $-3.0$ | -8.8 |  | $-2.4$ |  | $m A$ |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-105$ | -0.3 |  | $-10$ | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 03 |  | 10-5 | 0.3 |  | 10 | $\mu \mathrm{A}$ |

## AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{t}_{\mathrm{r} \mathrm{CL}}=\mathrm{t}_{\mathrm{r} C \mathrm{CL}}=20 \mathrm{~ns}$, uniess otherwise specified.

| PARAMETER |  | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL or TPLH | Propagation Delay Time From | $V_{D D}=5 \mathrm{~V}$ |  | 200 | 400 | ns |
|  | Clock to Q or $\overline{\mathrm{Q}}$ | $V_{D D}=10 \mathrm{~V}$ |  | 80 | 160 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 65 | 130 | ns |
| tPHL or tPLH | Propagation Delay Time From | $V_{D D}=5 \mathrm{~V}$ |  | 170 | 340 | ns |
|  | Set to $\overline{\mathrm{Q}}$ or Reset to Q | $V_{D D}=10 \mathrm{~V}$ |  | 70 | 140 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 55 | 110 | ns |
| tPHL or tPLH | Propagation Delay Time From | $V_{D D}=5 \mathrm{~V}$ |  | 110 | 220 | ns |
|  | Set to Q or Reset to $\overline{\mathrm{Q}}$ | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| $\mathrm{t}_{\text {s }}$ | Minimum Data Set-Up Time | $V_{D D}=5 \mathrm{~V}$ |  | 135 | 270 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 55 | 110 | ns |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 45 | 90 | ns |
| ${ }^{\text {t }}$ HL or tTLH | Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| ${ }^{\mathrm{f}} \mathrm{CL}$ | Maximum Clock Frequency | $V_{D D}=5 \mathrm{~V}$ | 2.5 | 5 |  | MHz |
|  | (Toggle Mode) | $V_{\text {DD }}=10 \mathrm{~V}$ | 6.2 | 12.5 |  | MHz |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 7.6 | 15.5 |  | MHz |
| $\mathrm{trCL}^{\text {or }} \mathrm{t} \mathrm{fCL}$ | Maximum Clock Rise and | $V_{D D}=5 \mathrm{~V}$ | 15 |  |  | $\mu \mathrm{s}$ |
|  | Fall Time | $V_{D D}=10 \mathrm{~V}$ | 10 |  |  | $\mu s$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 5 |  |  | $\mu \mathrm{s}$ |
| tw | Minimum Clock Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  | $(t W H=t W L)$ | $V_{D D}=10 \mathrm{~V}$ |  | 40 | 80 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 32 | 65 | ns |
| tWH | Minimum Set and Reset | $V_{D D}=5 \mathrm{~V}$ |  | 80 | 160 | ns |
|  | Pulse Width | $V_{D D}=10 \mathrm{~V}$ |  | 30 | 60 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 25 | 50 | ns |
| CIN | Average Input Capacitance | Any Input |  | 5 | 7.5 | pF |
| CPD | Power Dissipation Capacity | Per Flip-Flop (Note 3) |  | 35 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $V_{S S}=0 V$ unless otherwise specified.
Note 3: CPD determines the no load ac power consumption of any CMOS device. For complete explanation, see 54C/74C Family Characteristics application note AN-90.


Shift Registers


Truth Table

| ${ }^{\prime} \mathrm{t}_{\mathrm{n}-1}$ INPUTS |  |  |  |  |  | ${ }^{*} t_{n}$ OUTPUTS |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CL* | J | K | s | R | o | o | $\overline{\mathrm{o}}$ |  |
| J | 1 | $\times$ | 0 | 0 | $\bigcirc$ | 1 | o |  |
| 5 | $\times$ | 0 | 0 | 0 | 1 | 1 | O |  |
| J | 0 | $\times$ | 0 | 0 | 0 | 0 | 1 |  |
| - | $x$ | 1 | 0 | 0 | 1 | 0 | 1 |  |
| 7 | $x$ | $x$ | 0 | 0 | $x$ |  |  | (No change) |
| x | $x$ | $x$ | 1 | 0 | $x$ | 1 | o |  |
| $x$ | $x$ | $x$ | 0 | 1 | $x$ | 0 | 1 |  |
| x | $x$ | X | 1 | 1 | $\times$ | 1 | 1 |  |

Where: $\quad I=$ High Level
$\mathrm{O}=$ Low Level
A = Level Change
$X=$ Don't Care

- $=t_{n-1}$ refers to the time interval prior to the positive clock pulse transition
- $=t_{n}$ refers to the time intervals after the positive clock pulse transition


## CD4028BM/CD4028BC BCD-to-Decimal Decoder

## General Description

The CD4028BM/CD4028BC is a BCD-to-decimal or binary-to-octal decoder consisting of 4 inputs, decoding logic gates, and 10 output buffers. A BCD code applied to the 4 inputs, $A, B, C$, and $D$, results in a high level at the selected 1-of-10 decimal decoded outputs. Similarly, a 3-bit binary code applied to inputs $A, B$, and $C$ is decoded in octal at outputs 0-7. A high level signal at the $D$ input inhibits octal decoding and causes outputs $0-7$ to go low.

All inputs are protected against static discharge damage by diode clamps to $V_{D D}$ and $V_{S S}$.

## Features

- Wide supply voltage range 3.0 V to 15 V $0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
- High noise immunity
- Low power TTL compatibility
fan out of 2 driving 74L or 1 driving 74LS
- Low power
- Glitch free outputs
- "Positive logic" on inputs and outputs


## Applications

- Code conversion
- Address decoding
- Indicator-tube decoder


## Logic and Connection Diagrams



Dual-In-Line and Flat Package


Truth Table


## Absolute Maximum Ratings (Note 1)

(Notes 1 and 2)

| $V_{\text {DD }}$ Supply Voltage | -0.5 to +18 V |
| :---: | :---: |
| $V_{\text {IN }}$ Input Voltage | -0.5 to $\mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}$ |
| $\mathrm{T}_{\text {S }}$ Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| $\mathrm{P}_{\mathrm{D}}$ Package Dissipation | 500 mW |
|  | $300^{\circ} \mathrm{C}$ |

Recommended Operating Conditions
(Note 2)
$\begin{array}{lr}V_{\text {DD }} \text { Supply Voltage } & 3 \text { to } 15 \mathrm{~V} \\ V_{\text {IN }} \text { Input Voltage } & 0 \text { to } \mathrm{V}_{\mathrm{DD}} \\ \text { TA Operating Temperature Range }^{\text {CD4028BM }} & \\ \text { CD4028BC } & -55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \\ & -40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C}\end{array}$

DC Electrical Characteristics CD4028BC (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| ${ }^{\prime} \mathrm{DD}$ | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 5 |  | 0.01 | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  |  |  | 10 |  | 0.01 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  |  |  | 20 |  | 0.02 | 20 |  | 600 | $\mu \mathrm{A}$ |
| $V_{O L}$ | Low Level Output Voltage | $\left\\|\\|_{O} \mid<1 \mu A, V_{I L}=0 \mathrm{~V}, \mathrm{~V}_{1 H}=V_{D D}\right.$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\left\|\mathrm{I}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}, \mathrm{~V}_{\text {IL }}=0 \mathrm{~V}, \mathrm{~V}_{\text {IH }}=\mathrm{V}_{\text {DD }}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {DD }}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level Input Voltage | \|iol $<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{O}=1 \mathrm{~V}$ or 9 V | . | 3.0 |  | 4.5 | 3.0 | , | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{1} \mathrm{H}$ | High Level Input Voltage | $\\|_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| ${ }^{\prime} \mathrm{OL}$ | Low Level Output Current | $\mathrm{V}_{\text {IL }}=0 \mathrm{~V}, \mathrm{~V}_{\text {IH }}=\mathrm{V}_{\text {DD }}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 1.0 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.6 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 6.8 |  | 2.4 |  | $m A$ |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $\mathrm{V}_{\text {IL }}=0 \mathrm{~V}, \mathrm{~V}_{\text {IH }}=V_{\text {DD }}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.25 |  | -0.2 | -0.4 |  | -0.14 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -0.62 |  | -0.5 | -1.0 |  | -0.35 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -1.8 |  | -1.5 | -3.0 |  | -1.1 |  | $m A$ |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | $-1.0$ | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

## DC Electrical Characteristics CD4028BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\mathrm{V}_{\text {DD }}=5 \mathrm{~V}$ |  | 20 |  | 0.01 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.01 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 0.02 | 80 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\|\mathrm{OO}\|<1 \mu \mathrm{~A}, \mathrm{~V}_{\text {IL }}=0 \mathrm{~V}, \mathrm{~V}_{\text {IH }}=\mathrm{V}_{\text {DD }}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $\left\|\|O\|<1 \mu \mathrm{~A}, \mathrm{~V}_{\text {IL }}=0 \mathrm{~V}, \mathrm{~V}_{\text {IH }}=V_{\text {DD }}\right.$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| $V_{\text {IL }}$ | Low Level Input Voltage | $\|\mathrm{OO}\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | v |

## DC Electrical Characteristics (Cont'd.) CD4028BC (Note 2)

|  | PARAMETER | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| $\mathrm{V}_{\text {IH }}$ | High Level Input Voltage | $\mid 10 \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 |  |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  | . | 11.0 |  | v |
| IOL | Low Level Output Current | $V_{I H}=V_{D D}, V_{\text {IL }}=0 V$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\text {DD }}=5 \mathrm{~V}, ~ \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.2 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 6.0 |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{1 H}=V_{\text {DD }}, V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, ~ V_{0}=4.6 \mathrm{~V}$ | -0.2 |  | -0.16 | -0.32 |  | -0.12 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -0.5 |  | -0.4 | -0.8 |  | -0.3 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -1.4 |  | -1.2 | -2.4 |  | -1.0 |  | mA |
| In | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ | -0.3 |  |  | -0.3 |  |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  |  |  | 0.3 |  |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, R_{L}=200 \mathrm{k}$, Input $t_{r}=t_{f}=20 \mathrm{~ns}$, unless otherwise specified

| PARAMETER |  | CONDITIONS | MIN | TYP | MAX |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL or tPLH | Propagation Delay | $\mathrm{V}_{\text {CC }}=5 \mathrm{~V}$ |  | 240 | 480 | ns |
|  |  | $V_{C C}=10 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{C C}=15 \mathrm{~V}$ |  | 70 | 140 | ns |
| ${ }^{\text {t }}$ THL or tTLH | Transition Time | $V_{C C}=5 \mathrm{~V}$ |  | 175 | 350 | ns |
|  |  | $V_{C C}=10 \mathrm{~V}$ |  | 75 | 150 | ns |
|  |  | $V_{C C}=15 \mathrm{~V}$ |  | 60 | 110 | ns |
| $\mathrm{CIN}^{\text {N }}$ | Input Capacitance | Any Input | , | 5 | 7.5 | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

## Switching Time Waveforms



## CD4029BM/CD4029BC Presettable Binary/Decade Up/Down Counter

## General Description

The CD4029BM/CD4029BC is a presettable up/down counter which counts in either binary or decade mode depending on the voltage level applied at binary/decade input. When binary/decade is at logical " 1 ," the counter counts in binary, otherwise it counts in decade. Similarly, the counter counts up when the up/down input is at logical " 1 " and vice versa.

A logical " 1 " preset enable signal allows information at the " $j a m$ " inputs to preset the counter to any state asynchronously with the clock. The counter is advanced one count at the positive-going edge of the clock if the carry in and preset enable inputs are at logical " 0 ." Advancement is inhibited when either or both of these two inputs is at logical "1." The carry out signal is normally at logical " 1 " state and goes to logical " 0 " state when the counter reaches its maximum count in
the "up" mode or the minimum count in the "down" mode provided the carry input is at logical " 0 " state.

All inputs are protected against static discharge by diode clamps to both $V_{D D}$ and $V_{S S}$.

## Features

- Wide supply voltage range

3 V to 15 V

- High noise immunity
- Low power
$0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)

TTL compatibility
an out of 2
driving 74L
or 1 driving 74LS

- Parallel jam inputs
- Binary or BCD decade up/down counting


## Logic Diagram



Absolute Maximum Ratings
(Notes 1 and 2)
$V_{\text {DD }}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
PD Package Dissipation
$\mathrm{T}_{\mathrm{L}}$ Lead Temperature (Soldering, 10 seconds)
-0.5 to $+18 V_{D C}$
-0.5 to $V_{D D}+0.5 V_{D C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$300^{\circ} \mathrm{C}$

Recommended Operating Conditions
(Note 2)
$V_{\text {DD }}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4029BM CD4029BC
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## DC Electrical Characteristics CD4029bm (Note 2)



DC Electrical Characteristics CD4029BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 20 |  |  | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  |  | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  |  | 80 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\mathrm{IIO}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $1101<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |

DC Electrical Characteristics（Cont＇d．）CD4029BC（Note 2）

|  | PARAMETER | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| $V_{\text {IL }}$ | Low Level Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  |  | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | v |
| $\mathrm{V}_{\text {IH }}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 |  |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | V |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{0}=4.6 \mathrm{~V}$ | －0．52 |  | －0．44 | －0．88 |  | －0．36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | －1．3 |  | －1．1 | －2．25 |  | －0．9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | －3．6 |  | －3．0 | －8．8 |  | －2．4 |  | mA |
| IN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | －0．3 |  | $-10^{-5}$ | －0．3 |  | －1．0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}$ ，Input $\mathrm{t}_{\mathrm{rCL}}=\mathrm{t}_{\mathrm{fCL}}=20 \mathrm{~ns}$ ， unless otherwise specified

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| CLOCKED OPERATION |  |  |  |  |  |
| tPHL or tPLH Propagation Delay Time to Q Outputs | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 200 \\ & 85 \\ & 70 \end{aligned}$ | $\begin{aligned} & 400 \\ & 170 \\ & 140 \end{aligned}$ | ns <br> ns <br> ns |
| tpHL or tplH Propagation Delay Time to Carry Output | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 320 \\ & 135 \\ & 110 \end{aligned}$ | $\begin{aligned} & 640 \\ & 270 \\ & 220 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| tPHL or tPLH Propagation Delay Time to Carry Output | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, \quad C_{\mathrm{L}}=15 \mathrm{pF} \\ & V_{D D}=10 \mathrm{~V}, C_{\mathrm{L}}=15 \mathrm{pF} \\ & V_{D D}=15 \mathrm{~V}, C_{\mathrm{L}}=15 \mathrm{pF} \end{aligned}$ |  | $\begin{aligned} & 285 \\ & 120 \\ & 95 \end{aligned}$ | $\begin{aligned} & 570 \\ & 240 \\ & 190 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| tTHL or tTLH Transition Time／Q or Carry Output | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | ， | $\begin{aligned} & 100 \\ & 50 \\ & 40 \end{aligned}$ | $\begin{aligned} & 200 \\ & 100 \\ & 80 \end{aligned}$ | ns <br> ns <br> ns |
| twh or twL Minimum Clock Pulse Width | $\begin{aligned} & V_{D D}=5 V \\ & V_{D D}=10 V \\ & V_{D D}=15 V \end{aligned}$ |  | $\begin{aligned} & 160 \\ & 70 \\ & 55 \end{aligned}$ | $\begin{aligned} & 320 \\ & 135 \\ & 110 \end{aligned}$ | ns ns ns |
| $\mathrm{t}_{\mathrm{r} C L}$ or $\mathrm{t}_{\mathrm{f} C L}$ Maximum Clock Rise and Fall Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 15 \\ & 10 \\ & 5 \end{aligned}$ |  |  | $\mu \mathrm{s}$ <br> $\mu \mathrm{s}$ <br> $\mu \mathrm{s}$ |
| ${ }^{\text {t }}$ SU $\quad$ Minimum Set－Up Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 180 \\ & 70 \\ & 55 \end{aligned}$ | $\begin{aligned} & 360 \\ & 140 \\ & 110 \end{aligned}$ | ns ns ns |
| ${ }^{\text {f }} \mathrm{CL} \quad$ Maximum Clock Frequency | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 3.7 \\ & 4.5 \end{aligned}$ | $\begin{aligned} & 3.1 \\ & 7.4 \\ & 9 \end{aligned}$ |  | MHz <br> MHz <br> MHz |
| $C_{I N}$ Average Input Capacitance <br> CPD Power Dissipation Capaci－ <br> tance <br>   | Any Input <br> Per Package，（Note 3） |  | $5$ $65$ | 7.5 | pF pF |
| PRESET ENABLE OPERATION |  |  |  |  |  |
| tPHL or tPLH Propagation Delay Time to O Output | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 285 \\ & 115 \\ & 95 \end{aligned}$ | $\begin{aligned} & 570 \\ & 230 \\ & 195 \end{aligned}$ | ns ns． ns |

AC Electrical Characteristics (Cont'd.) $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{trCL}^{\mathrm{C}}=\mathrm{t}_{\mathrm{f} C \mathrm{~L}}=20 \mathrm{~ns}$, unless otherwise specified


Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $V_{S S}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: CPD determines the no load ac power consumption of any CMOS device. For complete explanation, see 54C/74C Family Characteristics application note, AN-90.

## Connection Diagram





## Switching Time Waveforms




Carry out lines at the 2nd or later stages may have a negative－going spike due to dif－ ferential internal delays．These spikes do not affect counter operation，but if the carry out is used to trigger external circuitry the carry out should be gated with the clock．

## CD4030M／CD4030C Quad EXCLUSIVE－OR Gate

## General Description

The EXCLUSIVE－OR gates are monolithic complemen－ tary MOS（CMOS）integrated circuits constructed with N －and P－channel enhancement mode transistors．All inputs are protected against static discharge with diodes to $V_{D D}$ and $V_{S S}$ ．

## Features

－Wide supply voltage range
－Low power
－Medium speed operation
－High noise immunity

## Applications

－Automotive
m Industrial controls
－Data terminals
－Remote metering
－Computers

## Schematic Diagram



Connection Diagram

top view

## Absolute Maximum Ratings

Voltage at Any Pin（Note 1）
Operating Temperature Range CD4030M CD4030C
Storage Temperature Range
Package Dissipation
Operating $\mathrm{V}_{\mathrm{DD}}$ Range
Lead Temperature（Soldering， 10 seconds）

$$
V_{S S}-0.3 V \text { to } V_{S S}+15.5 \mathrm{~V}
$$

$$
-55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C}
$$

$$
-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C}
$$

$$
-65^{\circ} \mathrm{C} \text { to }+150^{\circ} \mathrm{C}
$$

$$
500 \mathrm{~mW}
$$

$$
\mathrm{V}_{\mathrm{ss}}+3.0 \mathrm{~V} \text { to } \mathrm{V}_{\mathrm{SS}}+15 \mathrm{~V}
$$

$300^{\circ} \mathrm{C}$

DC Electrical Characteristics CD4030M

| PARAMETER | CONDITIONS | LIMITS |  |  |  |  |  |  |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |
|  |  | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX |  |
| Quiescent Device | $V_{D D}=5.0 \mathrm{~V}$ |  |  | 0.5 |  | 0.005 | 0.5 |  |  | 30 | $\mu \mathrm{A}$ |
| Current（ $L_{L}$ ） | $V_{D D}=10 \mathrm{~V}$ |  |  | 1.0 |  | 0.01 | 1.0 |  |  | 60 | $\mu \mathrm{A}$ |
| Quiescent Device Dissı． | $V_{D D}=5.0 \mathrm{~V}$ |  |  | 2.5 |  | 0.025 | 2.5 |  |  | 150 | $\mu \mathrm{W}$ |
| pation Package（ $\mathrm{P}_{\mathrm{D}}$ ） | $V_{D D}=10 \mathrm{~V}$ |  |  | 10 |  | 0.1 | 10 |  |  | 600 | $\mu \mathrm{W}$ |
| Output Voltage Low | $V_{D D}=5.0 \mathrm{~V}$ |  |  | 0.05 |  | 0 | 0.05 |  |  | 0.05 | $v$ |
| Level（ $V_{\text {OL }}$ ） | $V_{D D}=10 \mathrm{~V}$ |  |  | 0.05 |  | 0 | 0.05 |  |  | 0.05 | v |
| Output Voltage High | $V_{D O}=5.0 \mathrm{~V}$ | 4.95 |  |  | 4.95 | 5.0 |  | 4.95 |  |  | $v$ |
| Level（ $\mathrm{V}_{\mathrm{OH}}$ ） | $V_{D O}=10 \mathrm{~V}$ | 9.95 |  |  | 9.95 | 10 |  | 9.95 |  |  | v |
| Noise Immunity | $V_{\text {DO }}=5.0 \mathrm{~V}$ | 1.5 |  |  | 1.5 | 2.25 |  | 1.4 |  |  | $v$ |
| （All Inputs）（ $\mathrm{V}_{\mathrm{NL}}$ ） | $V_{D D}=10 \mathrm{~V}$ | 3.0 |  |  | 3.0 | 4.5 |  | 2.9 |  |  | v |
| Noise Immunity | $V_{D D}=5.0 \mathrm{~V}$ | 1.4 |  |  | 1.5 | 2.25 |  | 1.5 |  |  | $v$ |
| （All Inputs）（ $\mathrm{V}_{\mathrm{NH}}$ ） | $V_{D D}=10 \mathrm{~V}$ | 2.9 |  |  | 3.0 | 4.5 |  | 3.0 |  |  | $v$ |
| Output Drive Current | $V_{\text {DD }}=5.0 \mathrm{~V}$ | 0.75 |  |  | 0.6 | 1.2 |  | 0.45 |  |  | mA |
| N －Channel（ $\mathrm{I}_{\mathrm{D}} \mathrm{N}$ ） | $V_{D D}=10 \mathrm{~V}$ | 1.5 |  |  | 1.2 | 2.4 |  | 0.9 |  |  | mA |
| Output Drive Current | $\mathrm{V}_{\text {D }}=5.0 \mathrm{~V}$ | －0．45 |  |  | －0．3 | －0．6 |  | －0．21 |  |  | $m A$ |
| P－Channel（ ${ }_{D} \mathrm{P}$ ） | $V_{D D}=10 \mathrm{~V}$ | －0．95 |  |  | －0．65 | －1．3 |  | －0．45 |  |  | mA |
| Input Current（ $i_{1}$ ） | $V_{1}=0 V$ or $V_{1}=V_{D D}$ |  |  |  |  | 10 |  |  |  |  | pA |

DC Electrical Characteristics CD4030C

| PARAMETER | CONDITIONS | L．IMITS |  |  |  |  |  |  |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |
|  |  | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX |  |
| Quiescent Device | $\mathrm{V}_{\text {DO }}=5.0 \mathrm{~V}$ |  |  | 5.0 |  | 0.05 | 5.0 |  |  | 70 | $\mu \mathrm{A}$ |
| Current（ $\mathrm{I}_{\text {L }}$ ） | $V_{D D}=10 \mathrm{~V}$ |  |  | 10 |  | 0.1 | 10 |  |  | 140 | $\mu \mathrm{A}$ |
| Quiescenı Device Dissi－ | $V_{\text {DD }}=5.0 \mathrm{~V}$ |  |  | 25 |  | 0.25 | 25 |  |  | 350 | $\mu \mathrm{W}$ |
| pation Package（ $P_{D}$ ） | $V_{D D}=10 \mathrm{~V}$ |  |  | 100 |  | 1.0 | 100 |  |  | 1，400 | $\mu \mathrm{W}$ |
| Output Voltage Low | $\mathrm{V}_{\text {DD }}=5.0 \mathrm{~V}$ |  |  | 0.05 |  | 0 | 0.05 |  |  | 0.05 | $v$ |
| Level（ $\mathrm{V}_{\mathrm{OL}}$ ） | $V_{D D}=10 \mathrm{~V}$ |  |  | 0.05 |  | 0 | 0.05 |  |  | 0.05 | V |
| Output Voltage High | $V_{\text {DO }}=5.0 \mathrm{~V}$ | 4.95 |  |  | 4.95 | 5.0 |  | 4.95 |  |  | V |
| Level（ $\mathrm{V}_{\mathrm{OH}}$ ） | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  |  | 9.95 | 10 |  | 9.95 |  |  | $\checkmark$ |
| Noise Immunity | $V_{D D}=5.0 \mathrm{~V}$ | 1.5 |  |  | 1.5 | 2.25 |  | 1.4 |  |  | v |
| （All Inputs）（ $\mathrm{V}_{\text {NL }}$ ） | $V_{D D}=10 \mathrm{~V}$ | 3.0 |  |  | 3.0 | 4.5 |  | 2.9 |  |  | V |
| Noise Immunity | $V_{\text {DO }}=5.0 \mathrm{~V}$ | 1.4 |  |  | 1.5 | 2.25 |  | 1.5 |  |  | V |
| （All Inputs）（ $\mathrm{V}_{\mathrm{NH}}$ ） | $V_{D D}=10 \mathrm{~V}$ | 2.9 |  |  | 3.0 | 4.5 |  | 3.0 |  |  | V |
| Output Drive Current | $V_{D O}=5.0$ | 0.35 |  |  | 0.3 | 1.2 |  | 0.25 |  |  | mA |
| N －Channel（ $\mathrm{I}_{\mathrm{D}} \mathrm{N}$ ） | $V_{D D}=10 \mathrm{~V}$ | 0.7 |  |  | 0.6 | 2.4 |  | 0.5 |  |  | mA |
| Output Drive Current | $V_{\text {DD }}=5.0 \mathrm{~V}$ | －0．21 |  |  | －0．15 | －0．6 |  | －0．12 |  |  | mA |
| P－Channel（ $1_{0} \mathrm{P}$ ） | $V_{D D}=10 \mathrm{~V}$ | －0．45 |  |  | －0．32 | －1．3 |  | $-0.25$ |  |  | mA |
| Input Current（ $1_{1}$ ） | $V_{1}=0 V$ or $V_{1}=V_{D D}$ |  |  |  |  | 10 |  |  |  |  | pA |

Note 1：This device should not be connected to circuits with power on because high transient voltages may cause permanent damage．

## AC Electrical Characteristics CD4030M

| PARAMETER | CONDITIONS | LIMITS |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP | MAX |  |
| Propagation Delay Time ( $\mathrm{t}_{\text {PHL }}$ ) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 40 \end{aligned}$ | $\begin{aligned} & 200 \\ & 100 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| Propagation Delay Time ( $\mathrm{t}_{\text {PLH }}$ ) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 40 \end{aligned}$ | $\begin{aligned} & 200 \\ & 100 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| Transition Time High to Low | $V_{D D}=5.0 \mathrm{~V}$ $V_{D D}=10 \mathrm{~V}$ |  | 70 25 | 150 75 | ns |
| Level ( $\mathrm{t}_{\text {THL }}$ ) | $V_{D D}=10 \mathrm{~V}$ |  | 25 | 75 | ns |
| Transition Time Low to High | $V_{D D}=5.0 \mathrm{~V}$ $V_{D D}=10 \mathrm{~V}$ |  | $\begin{array}{r}80 \\ \\ \hline\end{array}$ | 150 | ns |
| Level ( $\mathrm{T}_{\text {LLH }}$ ) | $V_{D D}=10 \mathrm{~V}$ |  | 30 | 75 | ns |
| Input Capacitance ( $\mathrm{C}_{1}$ ) | $V_{1}=0 V$ or $V_{1}=V_{D D}$ |  | 5.0 |  | pF |

## AC Electrical Characteristics CD4030C

| PARAMETER | CONDITIONS | LIMITS |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP | MAX |  |
| Propagation Delay Time ( $\mathrm{t}_{\text {PHL }}$ ) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 40 \end{aligned}$ | $\begin{aligned} & 300 \\ & 150 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| Propagation Delay Time (tpLH) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 40 \end{aligned}$ | $\begin{aligned} & 300 \\ & 150 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| Transition Time High to Low | $V_{D D}=5.0 \mathrm{~V}$ |  | 70 | 300 | ns |
| Level ( $\mathrm{T}_{\text {THL }}$ ) | $V_{D D}=10 \mathrm{~V}$ |  | 25 | 150 | ns |
| Transition Time Low to High | $V_{\text {DD }}=5.0 \mathrm{~V}$ |  | 80 | 300 | ns |
| Level ( $\mathrm{T}_{\text {LLH }}$ ) | $V_{D D}=10 \mathrm{~V}$ |  | 30 | 150 | ns |
| Input Capacitance ( $\mathrm{C}_{1}$ ) | $V_{1}=0 \mathrm{~V}$ or $\mathrm{V}_{1}=\mathrm{V}_{\mathrm{DD}}$ |  | 5.0 |  | pF |

Truth Table (For One of Four Identical Gates)

| A | B | J |
| :---: | :---: | :---: |
| 0 | 0 | 0 |
| 1 | 0 | 1 |
| 0 | 1 | 1 |
| 1 | 1 | 0 |
| Where: | = |  |

National
Semiconductor

## CD4031BM/CD4031BC 64-Stage Static Shift Register

## General Description

The CD4031BM/CD4031BC is an integrated, complementary MOS (CMOS), 64-stage, fully static shift register. Two data inputs, DATA IN and RECIRCULATE IN, and a MODE CONTROL input are provided. Data at the DATA input (when MODE CONTROL is low) or data at the RECIRCULATE input (when MODE CONTROL is high), which meets the setup and hold time requírements, is entered into the first stage of the register and is shifted one stage at each positive transition of the CLOCK.
Data output is available in both true and complement forms from the 64th stage. Both the DATA OUT (Q) and DATA OUT $(\bar{Q})$ outputs are fully buffered.

The CLOCK input of the CD4031BM/CD4031BC is fully buffered, and present only a standard input load capacitance. However, a DELAYED CLOCK OUTPUT (CLD) has been provided to allow reduced clock drive fan-out and transition time requirements when cascading packages.

Features

| Wide supply voltage range | 3.0 V to 15 V |
| :--- | ---: |
| High noise immunity | $0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.) |
| Low power TTL | fan out of 2 driving 74 L |
| compatibility | or 1 driving 74 LS |
| ally static operation | DC to 8 MHz |
| Fully buffered clock input | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ (typ.) |
|  | 5 pF (typ.) |
| input capacitance |  |

- Single phase clocking requirements
- Delayed clock output for reduced clock drive requirements
- Fully buffered outputs
- High current sinking capability 1.6 mA Q output @ $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ and $25^{\circ} \mathrm{C}$

Logic and Connection Diagrams



## Absolute Maximum Ratings

(Notes 1 and 2)

| $V_{D D}$ Supply Voltage | -0.5 V to +18 V |  |
| :--- | :--- | ---: |
| $\mathrm{~V}_{\text {IN }}$ | Input Voltage | -0.5 V to $\mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}$ |
| $\mathrm{~T}_{\mathrm{S}}$ | Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| $\mathrm{P}_{\mathrm{D}}$ | Package Dissipation | 500 mW |
| $T_{L}$ | Lead Temperature (Soldering, | 10 seconds) |
|  | $300^{\circ} \mathrm{C}$ |  |

Recommended Operating Conditions
(Note 2)

| $V_{\text {DD }}$ Supply Voltage | +3 V to +15 V |
| :--- | ---: |
| $\mathrm{~V}_{\text {IN }}$ Input Voltage | 0 V to $\mathrm{V}_{\mathrm{DD}}$ |
| $\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range |  |
|  | CD4031BM |
|  | CD4031BC |

DC Electrical Characteristics (Note 2) CD4031BM

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 5 |  | 0.01 | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  |  |  | 10 |  | 0.01 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  |  |  | 20 |  | 0.02 | 20 |  | 600 | $\mu \mathrm{A}$ |
| V ${ }_{\text {OL }}$ | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  | $\left.\mathrm{V}_{\text {DD }}=10 \mathrm{~V}\right\} \mathrm{V}_{1 H}=\mathrm{V}_{\mathrm{DD}}, \mathrm{V}_{1 L}=0 \mathrm{~V}, \\|_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | $\begin{aligned} & 4.95 \\ & 9.95 \\ & 14.95 \end{aligned}$ |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $\left.V_{D D}=10 \mathrm{~V}\right\} \mathrm{V}_{1 H}=\mathrm{V}_{\text {DD }}, V_{1 L}=0 \mathrm{~V}, \mathrm{l}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ ( ${ }^{\text {d }}$ |  |  | 14.95 | 15 |  | 14.95 |  | v |
| VIL | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | v |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or $9.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | v |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $V_{1 H}$ | High Level Input Voltage |  | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | $v$ |
|  |  |  | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| IOL | Low Level Output Current, Q Output | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}, V_{1 H}=V_{D}$ | 2.3 |  | 1.9 | 3.8 |  | 1.3 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{H}}=\mathrm{V}^{\text {DD }}$ | 5.1 |  | 4.2 | 8.4 |  | 2.8 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ ) $\mathrm{V}^{\text {dL }}$ | 10.5 |  | 8.8 | 17 |  | 6.1 |  | mA |
| IOL | Low Level Output Current, $\overline{\mathrm{Q}}$ and $\mathrm{CL}_{\mathrm{D}}$ Outputs | $\left.V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V}\right) V_{1 H}=V$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | V $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}, ~ V_{\text {IH }}=\mathrm{V}_{\text {DD }}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$, $\mathrm{V}^{\text {IL }}=0 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current, All Outputs | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}, V_{1 H}=V^{\text {d }}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | V $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}, ~ V_{1 H}=\mathrm{V}_{\mathrm{DD}}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ ( ${ }^{\text {d }}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| 1 IN | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

## Truth Tables

MODE CONTROL (data selection)

| MODE <br> CONTROL | DATA <br> IN | RECIRCULATE <br> IN | DATA INTO <br> FIRST STAGE |
| :---: | :---: | :---: | :---: |
| 0 | 0 | X | 0 |
| 0 | 1 | X | 1 |
| 1 | X | 0 | 0 |
| 1 | X | 1 | 1 |

EACH STAGE

| $\mathrm{D}_{\mathbf{n}}$ | CL | $\mathbf{Q}_{\mathbf{n}}$ |
| :---: | :---: | :---: |
| 0 | - | 0 |
| 1 | - | 1 |
| X | $\checkmark$ | NC |

[^19]DC Electrical Characteristics (Note 2) CD4031BC

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| $I_{\text {DD }}$ | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 20 |  | 0.01 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  |  |  | 40 |  | 0.01 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  |  |  | 80 |  | 0.02 | 80 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $\left(\begin{array}{l} V_{D D}=5 \mathrm{~V} \\ V_{D D}=10 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{array}\right\} \mathrm{V}_{I H}=\mathrm{V}_{\mathrm{DD}}, \mathrm{~V}_{\mathrm{IL}}=0 \mathrm{~V},\| \|_{\mathrm{O}}<1 \mu \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\left.\begin{array}{l} V_{D D}=5 \mathrm{~V} \\ V_{D D}=10 \mathrm{~V} \\ V_{D D}=15 \mathrm{~V} \end{array}\right\} \mathrm{V}_{1 H}=\mathrm{V}_{D D}, V_{I L}=0 \mathrm{~V},\left\|\left.\right\|_{O}\right\|<1 \mu \mathrm{~A}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  |  | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  |  | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level Input Voltage | $\left.\begin{array}{l} V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V} \\ V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V} \\ V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V} \text { or } 13.5 \mathrm{~V} \end{array}\right\} \mid{ }_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  |  |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  |  |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{\text {IH }}$ | High Level Input Voltage | $\left.\left\{\begin{array}{l} V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V} \\ V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V} \\ V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V} \text { or } 13.5 \mathrm{~V} \end{array}\right\} \right\rvert\, \mathrm{IO}_{\mathrm{O}}<1 \mu \mathrm{~A}$ | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  |  |  | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | v |
|  |  |  | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| IOL | Low Level Output Current, Q Output | $\left\{\begin{array}{l} V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V} \\ V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \\ V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V} \end{array}\right\} \mathrm{V}_{1 \mathrm{H}}=\mathrm{V}_{\mathrm{DD}}=0 \mathrm{~V}$ | 1.8 |  | 1.6 | 3.8 |  | 1.3 |  | mA |
|  |  |  | 4.0 |  | 3.5 | 8.4 |  | 2.8 |  | mA |
|  |  |  | 8.7 |  | 7.5 | 17 |  | 6.1 |  | mA |
| IOL | Low Level Output Current, $\overline{\mathrm{O}}$ and $\mathrm{CL}_{\mathrm{D}}$ Outputs | $\left.\begin{array}{l} V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V} \\ V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \\ V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V} \end{array}\right\} V_{1 \mathrm{H}}=\mathrm{V}_{\mathrm{DD}}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  |  | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  |  | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| 1 OH | High Level Output Current, All Outputs | $\left.\begin{array}{l} V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V} \\ V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V} \\ V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V} \end{array}\right\} V_{1 \mathrm{H}}=V_{D D}=0 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  |  | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  |  | -3.6 |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| In | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

## Switching Time Waveforms



AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}$, Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {PHL }}$ t PLLH | Propagation Delay, Time, Clock to Q and $\overline{\mathrm{Q}}$ | $\mathrm{V}_{\text {CC }}=5 \mathrm{~V}$ |  | 300 | 600 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ |  | 125 | 250 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 100 | 200 | ns |
| $\mathrm{t}_{\text {PHL }} \mathrm{t}_{\text {PLH }}$ | Propagation Delay Time, Clock to $\mathrm{CL}_{\text {D }}$ | $\mathrm{V}_{\text {CC }}=5 \mathrm{~V}$ |  | 125 | 250 | ns |
|  |  | $\mathrm{V}_{\mathrm{cc}}=10 \mathrm{~V}$ |  | 60 | 125 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 50 | 100 | ns |
| ${ }^{\text {t }}$ thL, $\mathrm{t}_{\text {TLH }}$ | Output Transition Time, All Outputs | $\mathrm{V}_{\mathrm{cc}}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $\mathrm{V}_{\mathrm{cc}}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $\mathrm{V}_{\mathrm{cc}}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| $\begin{aligned} & \mathrm{tsu}_{0} \\ & \mathrm{tsu}_{1} \end{aligned}$ | Minimum Data Setup Time, DATA IN or RECIRCULATE IN to Clock | $\mathrm{V}_{\text {cC }}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $\mathrm{V}_{\mathrm{cc}}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| $\mathrm{tH}_{\mathrm{H}}$ | Minimum Data Hold Time, Clock to DATA INor RECIRCULATE IN | $\mathrm{V}_{\text {CC }}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
| ${ }^{\text {t }}{ }_{1}$ |  | $\mathrm{V}_{\mathrm{cc}}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $\mathrm{V}_{\mathrm{cc}}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| ${ }^{\text {twL }}$, twh | Minimum Clock Pulse Width | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ |  | 150 | 300 | ns |
|  |  | $\mathrm{V}_{\mathrm{cc}}=10 \mathrm{~V}$ |  | 60 | 125 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$ |  | 50 | 100 | ns |
| ${ }_{\mathrm{C}}^{\mathrm{CL}}$ | Maximum Clock Frequency | $\mathrm{V}_{\text {cC }}=5 \mathrm{~V}$ | 1.6 | 3.2 |  | MHz |
|  |  | $\mathrm{V}_{\mathrm{CC}}=10 . \mathrm{V}$ | 4.0 | 8.0 |  | MHz |
|  |  | $\mathrm{V}_{\mathrm{cc}}=15 \mathrm{~V}$ | 5.0 | 10 |  | MHz |
| ${ }_{\text {trCL, }}$ tFCL | Maximum Clock Input Rise and Fall Times (Note 3) | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ | 15 |  |  | $\mu \mathrm{s}$ |
|  |  | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ | 10 |  |  | $\mu \mathrm{s}$ |
|  |  | $\mathrm{V}_{\mathrm{cc}}=15 \mathrm{~V}$ | 5 |  |  | $\mu \mathrm{s}$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Any Input |  | 5 | 7.5 | pF |

Note 3: When clocking cascaded packages in parallel, one should insure that: $\mathrm{t}_{\mathrm{r}} \mathrm{CL} \leqslant 2\left(\mathrm{t}_{\mathrm{PD}}-\mathrm{t}_{\mathrm{H}}\right)$ where: $\mathrm{t}_{\mathrm{PD}}=$ the propagation delay of the driving stage and $\mathrm{t}_{\mathrm{H}}=$ the hold time of the driven stage.

## Block Diagram

cascading packages using DELAYED CLOCK (CLD) output


# CD4034BM/CD4034BC 8-State TRI-STATE ${ }^{\circledR}$ Bidirectional Parallel/Serial Input/Output Bus Register 

## General Description

The CD4034BM/CD4034BC is an 8-bit CMOS static shift register with two parallel bidirectional data ports ( $A$ and B) which, when combined with serial shifting operations, can be used to (1) bidirectionally transfer parallel data between two buses, (2) convert serial data to parallel form and direct them to either of two buses, (3) store (recirculate) parallel data, or (4) accept parallel data from either of two buses and convert them to serial form. These operations are controlled by five control inputs:

A ENABLE (AE): " $A$ " data port is enabled only when $A E$ is at logical " 1 ". This allows the use of a common bus for multiple packages.
A-BUS-TO-B-BUS/B-BUS-TO-A•BUS (A/B): This input controls the direction of data flow. When at logical " 1 ", data flows from port $A$ to $B$ ( $A$ is input, $B$ is output). When at logical " 0 ", the data flow direction is reversed.
ASYNCHRONOUS/SYNCHRONOUS (AIS): When AIS is at logical " 0 ", data transfer occurs at positive transition of the CLOCK. When A/S is at logical " 1 ", data transfer is independent of the CLOCK for parallel' operation. In serial mode, A/S input is internally disabled such that operation is always synchronous. (Asynchronous serial operation is not possible.)
PARALLELISERIAL (PIS): A logical " 1 " P/S input allows data transfer into the registers via A or B port (synchronous if A/S = logical " 0 ', asynchronous if A/S $=$ logical " 1 "). A logical " 0 " P/S allows serial data to transfer into the register synchronously with the positive transition of the CLOCK, independent of the A/S input.
CLOCK: Single phase, enabled only in synchronous mode. (Either P/S = logical " 1 " and A/S = logical " 0 " or $P / S=$ logical " 0 ".

All register stages are D-type master-slave flip-flops with separate master and slave clock inputs generated internally to allow synchronous or asynchronous data transfer from master to slave.

All inputs are protected against damage due to static discharge by diode clamps to $V_{D D}$ and $V_{S S}$.

## Features

- Wide supply voltage range 3.0 to 18 V
- High noise immunity
$0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
- Low power TTL compatibility
fan out of 2 driving 74L
or 1 driving 74LS
- RCA CD4034B second source


## Applications

- Parallel Input/Parallel Output Parallel Input/Serial Output Serial Input/Parallel Output Serial Input/Serial Output register
- Shift right/shift left register
- Shift right/shift left with parallel loading
- Address register
- Buffer register
- Bus system register with enable parallel lines at bus side
- Double bus register system
- Up-down Johnson or ring counter
- Pseudo-random code generators
- Sample and hold register (storge, counting, display)
- Frequency and phase comparator


## Connection Diagram



## Absolute Maximum Ratings

(Notes 1 and 2)
$V_{D D}$ DC Supply Voltage
$-0.5 V_{D C}$ to $+18 V_{D C}$
$V_{\text {IN }}$ Input Voltage $-0.5 V_{D C}$ to $V_{D D}+0.5 V_{D C}$
$\mathrm{T}_{\mathrm{S}} \quad$ Storage Temperature Range $\quad-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
$P_{D} \quad$ Package Dissipation
$T_{L}$ Lead.Temperature
(Soldering, 10 seconds)

Recommended Operating Conditions
(Note 2)
$V_{D D}$ DC Supply Voltage
$V_{\text {IN }}$ Input Voltage $\quad 0 V_{D C}$ to $V_{D D} V_{D C}$
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4034BM CD4034BC
$+3 V_{D C}$ to $+15 V_{D C}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## DC Electrical Characteristics CD4034BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 5 |  |  | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}$ |  | 10 |  |  | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  |  | 20 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {OL }}$ | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | v |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 |  |  | 4.95 |  | v |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}$ | 9.95 |  | 9.95 |  |  | 9.95 |  | V |
|  |  | $\mathrm{V}_{\text {DD }}=15 \mathrm{~V}$ | 14.95 |  | 14.95 |  |  | 14.95 |  | v |
| $V_{\text {IL }}$ | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | V |
|  |  | $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  |  | 3.0 |  | 3.0 | v |
|  |  | $\mathrm{V}_{\text {DD }}=15 \mathrm{~V}, \mathrm{VO}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | v |
| $\mathrm{V}_{1 H}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 |  |  | 7.0 |  | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15, \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | $\checkmark$ |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 |  |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 |  |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 |  |  | 2.4 |  | mA |
| IOH | High Level Output Current |  |  |  | -0.51 |  |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 |  |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 |  |  | -2.4 |  | mA |
| 1 IN | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -0.1 |  | -0.1 | $-10^{-5}$ |  | -1.0 |  | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |
|  | Tri-State Leakage Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0 \mathrm{~V}$ | -0.1 |  | -0.1 | $-10^{-5}$ |  | -1.0 |  | $\mu \mathrm{A}$ |
| $\underline{\mathrm{l}} \mathrm{OZ}$ |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics:' provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

## Logic Diagram



## DC Electrical Characteristics CD4034BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| $I_{\text {DD }}$ | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 20 |  |  | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  |  |  | 40 |  |  | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  |  |  | 80 |  |  | 80 |  | 600 | $\mu \mathrm{A}$ |
| VoL | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | v |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 |  |  | 4.95 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 |  |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 |  |  | 14.95 |  | $v$ |
| $V_{\text {IL }}$ | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | $v$ |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  |  | 3.0 |  | 3.0 | v |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | v |
| $V_{1 H}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | $v$ |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 |  |  | 7.0 |  | $v$ |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | V |
| ${ }^{1} \mathrm{OL}$ | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 |  |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 |  |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 |  |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 |  |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 |  |  | -0.9 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 |  |  | -2.4 |  | mA |
| 1 N | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ | -0.3 |  | -0.3 | $-10^{-5}$ |  | -1.0 |  | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu A$ |
|  | Tri-State Leakage Current | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0 \mathrm{~V}$ | -0.3 |  | -0.3 | $-10^{-5}$ |  | -1.0 |  | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, R_{L}=200 \mathrm{k}$, Input $t_{r}=t_{f}=20 \mathrm{~ns}$, unless otherwise specified

| PARAMETER |  | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {PHL }}, \mathrm{t}_{\text {PLH }}$ | Propagation Delay Time, $A(B)$ Synchronous Parallel Data or Serial Data Input, B(A) Parallel Data Output | $V_{D D}=5 \mathrm{~V}$ |  | 280 | 700 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 120 | 270 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 85 | 190 | ns |
| $\mathrm{t}_{\text {PHL }}, \mathrm{t}_{\text {PLH }}$ | Propagation Delay Time, $\mathrm{A}(\mathrm{B})$ A(B) Asynchronous Parallel Data Input, $B(A)$ Parallel Data Output | $V_{D D}=5 \mathrm{~V}$ |  | 280 | 700 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 120 | 270 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 85 | 190 | ns |
| $t_{\text {PHZ }}, t_{\text {PLZ }}$ | Propagation Delay Time from $A / B$ or $A E$ to High Impedance State at $A$ Outputs or from $A / B$ to High Impedance State at B Outputs | $V_{D D}=5 \mathrm{~V}, R_{L}=1.0 \mathrm{~K} \Omega$ |  | 95 | 220 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=1.0 \mathrm{~K} \Omega$ |  | 60 | 130 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=1.0 \mathrm{~K} \Omega$ |  | 45 | 100 | ns |
| $\mathrm{t}_{\text {PZH }}, \mathrm{t}_{\text {PZL }}$ | Propagation Delay Time from $A / B$ or AE to Logical " 1 " or Logical " 0 " State at $A$ Outputs or from $A / B$ to Logical "1" or Logical "0" State at B Outputs | $V_{D D}=5 \mathrm{~V}, R_{L}=1.0 \mathrm{~K} \Omega$ |  | 180 | 480 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}, R_{L}=1.0 \mathrm{~K} \Omega$ |  | 75 | 190 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=1.0 \mathrm{~K} \Omega$ |  | 55 | 140 | ns |
| ${ }^{\text {THL }}$, $\mathrm{t}_{\text {TLH }}$ | Output Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| ${ }^{\mathrm{f}} \mathrm{CL}$ | Maximum Clock Input Frequency | $V_{\text {DD }}=5 \mathrm{~V}$ | 2 | 4 |  | MHz |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 5 | 10 |  | MHz |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 7 | 14 |  | MHz |
| ${ }^{\text {W WL, }}$ t ${ }_{\text {WH }}$ | Minimum Clock Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 125 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 35 | 70 | ns |

## AC Electrical Characteristics (Cont'd.)

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{RCL}}, \mathrm{t}_{\mathrm{FCL}}$ | Maximum Clock Rise \& Fall Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 15 \\ & 15 \\ & 15 \end{aligned}$ |  |  | $\begin{aligned} & \mu \mathrm{s} \\ & \mu \mathrm{~s} \\ & \mu \mathrm{~s} \end{aligned}$ |
| ${ }^{\text {t }}$ U | Parallel (A or B) and Serial Data Setup Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 25 \\ & 10 \\ & 7 \end{aligned}$ | $\begin{aligned} & 70 \\ & 30 \\ & 20 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| tsu | Control Inputs AE, A/B, P/S, A/S Setup Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 110 \\ & 35 \\ & 20 \end{aligned}$ | $\begin{aligned} & 280 \\ & 100 \\ & 60 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| ${ }^{\text {twh }}$ | Minimum High Level $A E, A / B, P / S$, A/S Pulse Width | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 160 \\ & 70 \\ & 40 \end{aligned}$ | $\begin{aligned} & 400 \\ & 160 \\ & 90 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $C_{\text {IN }}$ | Average Input Capacitance | $A$ and $B$ Data $I / O$ and $A / B$ Control Input <br> Any Other Input |  | 7 5 | 15 $7.5$ | pF pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance | (Note 3) |  | 155 |  | pF |

Note 3: CPD determines the no-load power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note, AN-90.

## Schematic Diagram



Switching Time Waveforms and Test Circuits


A8 $\square$


$\mathrm{tr}_{\mathrm{r}, \mathrm{CL}}=\mathrm{tf}, \mathrm{CL}=20 \mathrm{~ns}$

Synchronous Operation


Asynchronous Operation


## Applications



Frequency and Phase Comparator



A "High" ("Low") on the Shift Left/Shift Right input allows serial data on the Shift Left Input (Shift Right Input) to enter the register on the positive transition of the clock signal. A "high" on the " $A$ " Enable Input disables the "A" parallel data lines on Registers 1 and 2 and enables the " $A$ " data lines on Registers 3 and 4
and allows parallel data into Registers 1 and 2. Other logic schemes may be used in place of registers 3 and 4 for parallel loading.

When parallel inputs are not used Registers 3 and 4 and associated logic are not required.

## Truth Table

| "A" ENABLE | P/S | A/B | A/S | MODE |  |
| :---: | :---: | :---: | :---: | :---: | :--- |
| 0 | 0 | 0 | X | Serial | Synchronous Serial data input, A- and B-Parallel data outputs disabled. |
| 0 | 0 | 1 | $X$ | Serial | Synchronous Serial data input, B-Parallel data output. |
| 0 | 1 | 0 | 0 | Parallel | B Synchronous Parallel data inputs, A-Parallel data outputs disabled. |
| 0 | 1 | 0 | 1 | Parallel | B Asynchronous Parallel data inputs, A-Parallel data.outputs disabled. |
| 0 | 1 | 1 | 0 | Parallel | A-Parallel data inputs disabled, B-Parallel data outputs, synchronous data recirculation. |
| 0 | 1 | 1 | 1 | Parallel | A-Parallel data inputs disabled, B-Parallel data outputs, asynchronous data recirculation. |
| 1 | 0 | 0 | $X$ | Serial | Synchronous Serial data input, A-Parallel data output. |
| 1 | 0 | 1 | $X$ | Serial | Synchronous Serial data inpút, B-Parallel data output. |
| 1 | 1 | 0 | 0 | Parallel | B Synchronous Parallel data input, A-Parallel data output. |
| 1 | 1 | 0 | 1 | Parallel | B Asynchronous Parallel data input, A-Parallel data output. |
| 1 | 1 | 1 | 0 | Parallel | A Synchronous Parallel data input, B-Parallel data output. |
| 1 | 1 | 1 | 1 | Parallel | A Asynchronous Parallel data input, B-Parallel data output. |

$x=$ Don't Care

* For synchronous operation (serial mode or when $\mathrm{A} / \mathrm{S}=0$ in parallel mode), outputs change state at positive transition of the clock.

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## CD4035BM/CD4035BC 4-Bit Parallel-In/Parallel-Out Shift Register

## General Description

The CD4035B 4-bit parallel-in/parallel-out shift register is a monlithic complementary MOS (CMOS) integrated circuit constructed with P - and N -channel enhancement mode transistors. This shift register is a 4-stage clocked serial register having provisions for synchronous parallel inputs to each stage and serial inputs to the first stage via $\sqrt{\bar{K}}$ logic. Register stages 2,3 , and 4 are coupled in a serial "D" flip-flop configuration when the register is in the serial mode (parallel/serial control low).
Parallel entry via the " $D$ " line of each register stage is permitted only when the parallel/serial control is "high".

In the parallel or serial mode, information is transferred on positive clock transitions.

When the true/complement control is "high", the true contents of the register are available at the output terminals. When the true/complement control is "low", the outputs are the complements of the data in the register. The true/complement control functions asynchronously with respect to the clock signal.
$\sqrt{\mathrm{K}}$ input logic is provided on the first stage serial input to minimize logic requirements particularly in counting and sequence-generation applications. With $\sqrt{\mathrm{K}}$ inputs connected together, the first stage becomes a "D" flip-flop. An asynchronous common reset is also provided.

Features

- Wide supply voltage range 3.0 V to 15 V
- High noise immunity $0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
- Low power TTL compatibility
fan out of 2 driving 74L
or 1 driving 74LS
- 4-stage clocked operation
- Synchronous parallel entry on all 4 stages
- $\sqrt{\mathrm{K}}$ inputs on first stage
- Asynchronous true/complement control on all outputs
- Reset Control
- Static flip-flop operation; master/slave configuration
- Buffered outputs
- Low power dissipation
$5 \mu \mathrm{~W}$ (typ.) (ceramic)
- High speed
to 5 MHz


## Applications

- Automotive
- Alarm systems
- Data terminals
- Industrial controls
- Instrumentation
- Remote metering
- Medical electronics
- Computers


## Logic Diagram



Absolute Maximum Ratings (Notes 1 and 2)
$V_{\text {DD }}$ dc Supply Voltage
-0.5 to +18 V
$V_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
$P_{D}$ Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
-0.5 to $V_{D D}+0.5 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$300^{\circ} \mathrm{C}$

Operating Conditions (Note 2)

## DC Electrical Characteristics CD4035BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 5 |  | 0.3 | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  | 0.5 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  | 1.0 | 20 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\mid \mathrm{lol}<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $\|\mathrm{IO}\|<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| VIL | Low Level Input Voltage | $\mid \mathrm{lol}<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  |  | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | $v$ |
| $\mathrm{V}_{\mathrm{IH}}$ | High Level Input Voltage | $\\| \mathrm{OL}<1.0 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 |  |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | $v$ |
| 1 OL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{0}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | $m \mathrm{~A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{0}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \quad V_{0}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{0}=4.6 \mathrm{~V}$ | -0.25 |  | -0.2 | 0.36 |  | -0.14 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \quad V_{0}=9.5 \mathrm{~V}$ | -0.62 |  | -0.5 | 0.9 |  | -0.35 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, ~ V_{O}=13.5 \mathrm{~V}$ | -1.8 |  | -1.5 | -3.5 |  | -1.1 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, ~ V_{I N}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \quad V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

## DC Electrical Characteristics CD4035BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 20 |  | 0.5 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 1.0 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 5.0 | 80 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\\| \mathrm{Ol}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $\left\|\mathrm{IO}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  |  | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | $v$ |
| $V_{\text {IL }}$ | Low Level Input Voltage | $\|\mathrm{OO}\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5. |  | 1.5 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  |  | 3.0 |  | 3.0 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | $v$ |
| $V_{\text {IH }}$ | High Level Input Voltage | $\\| \mathrm{O} \mid<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 |  |  | 7.0 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{0}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | v |

DC Electrical Characteristics (Cont'd.) CD4035BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IOL | Low Level Output Current |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| ${ }^{\mathrm{I}} \mathrm{H}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | -0.2 |  | -0.16 | -0.36 |  | -0.12 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \quad V_{O}=9.5 \mathrm{~V}$ | -0.5 |  | -0.4 | -0.9 |  | -0.3 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -1.4 |  | -1.2 | -3.5 |  | -1.0 |  | $m A$ |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \quad V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

## AC Electrical Characteristics

$T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}, \mathrm{t}_{\mathrm{r}}$ and $\mathrm{tf}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CLOCKED OPERATION |  |  |  |  |  |  |
| tPHL, tPLH | Propagation Delay Time | $V_{D D}=5 \mathrm{~V}$ |  | 250 | 500 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 75 | 150 | ns |
| ${ }^{\text {t }}$ HL | Transition Time High Low to High | $V_{D D}=5 \mathrm{~V}$ |  | 90 | 175 | ns |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}$ |  | 50 | 75 | ns |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 40 | 60 | ns |
| tTLH | Transition Time Low to High | $V_{D D}=5 \mathrm{~V}$ |  | 135 | 270 | us |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 70 | 140 | IT, |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 60 | 120 | (1). |
| tWL, tWH | Minimum Clock Pulse Width | $V_{\text {DD }}=5 \mathrm{~V}$ | 335 | 135 |  | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 165 | 50 |  | ns |
|  |  | $V D D=15 \mathrm{~V}$ | 100 | 40 |  | ns |
| $t_{r} C L, t_{f C L}$ | Ciock Rise and Fall Time | $V_{D D}=5 \mathrm{~V}$ |  |  | 15 | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  |  | 10 | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  |  | 5 | $\mu \mathrm{s}$ |
| ts | Minimum Set-upTime $\mathrm{J} / \overline{\mathrm{K}}$ Lines |  |  |  |  |  |
|  |  | $V_{D D}=5 V$ |  | 250 | 500 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 80 | 160 | ns |
| ${ }^{\text {t }}$ | Parallel-In Lines | $V_{D D}=5 V$ |  | 250 | 500 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 | 160 | ns |
| ${ }^{\text {t }}$ | P/S Control | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V V_{D D}=10 \mathrm{~V}$ |  | 40 | 80 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 35 | 60 | ns |
| ${ }^{\prime}$ MAX | Maximum Clock Frequency | $V_{D D}=5 \mathrm{~V}$ | 1.5 | 2.5 |  | MHz |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 3 | 6 |  | MHz |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 5 | 9 |  | MHz |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Any Input |  | 5 | 7.5 | pF |
| RESET OPERATION |  |  |  |  |  |  |
| tPHL, tPLH | Propagation Delay Time | $V_{D D}=5 V$ |  | 300 | 500 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 150 | 200 | ns |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 85 | 150 | ns |
| tWH | Minimum Reset Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 75 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 30 | 110 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 25 | 80 | ns |

CD4035BM/CD4035BC

Truth Table
Connection Diagram

| $c_{L}$ | $t_{n}-1$ (INPUTS) |  |  |  | $t_{n}$ (OUTPUTS) |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | J | $\overline{\mathrm{k}}$ | R | $\mathrm{a}_{\mathrm{n}-1}$ | $\mathrm{a}_{\mathrm{n}}$ |
| $\bigcirc$ | 0 | x | 0 | 0 | 0 |
| - | 1 | x | 0 | 0 | 1 |
| 」 | x | 0 | 0 | 1 | 0 |
| - | 1 | 0 | 0 | $\mathrm{a}_{\mathrm{n}-1}$ | $\overline{\mathrm{a}_{n-1}} \text { TOGGEE }$ |
| 」 | x | 1 | 0 | 1 | 1 |
| L | x | x | 0 | $\mathrm{a}_{\mathrm{n}-1}$ | $\mathrm{a}_{\mathrm{n}-1}$ |
| x | $\times$ | $\times$ | 1 | $\times$ | 0 |

Switching Time Waveforms


T/C Input Low
Reset Input Low

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## CD4041M/CD4041C Quad True/Complement Buffer

## General Description

The CD4041M/CD4041C is a quad true/complement buffer consisting of N - and P -channel enhancement mode transistors having low-channel resistance and high current (sourcing and sinking) capability. The CD4041 is intended for use as a buffer, line driver, or CMOS-to-TTL driver.

All inputs are protected from static discharge by diode clamps to $V_{D D}$ and $V_{S S}$.

Features

- Wide supply voltage range
3.0 V to 15 V
- High noise immunity $40 \% V_{D D}$ (typ.)
- True output

High current source and sink capability 8 mA (typ.) @ $\mathrm{V}_{\mathrm{O}}=9.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}$ 3.2 mA (typ.) @ $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V}$ (two TTL loads)

■ Complement output
Medium current source and sink capability 3.6 mA (typ.) @ $\mathrm{V}_{\mathrm{O}}=9.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}$ 1.6 mA (typ.) @ $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V}$

## Connection Diagram

Dual-In-Line and Flat Package


Schematic Diagram


1 of 4 Identical Units

## Absolute Maximum Ratings

(Notes 1 and 2)
$V_{D D}$ Supply Voltage
-0.5 V to +18 V
-0.5 V to $\mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$300^{\circ} \mathrm{C}$

VIN Input Voltage
TS Storage Temperature Range
$P_{D}$ Package Dissipation
$\mathrm{T}_{\mathrm{L}}$ Lead Temperature (Soldering, 10 seconds)
(Note 2)
$V_{\text {DD }}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4041M
CD4041C

3 V to 15 V O to $\mathrm{V}_{\mathrm{DD}}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

DC Electrical Characteristics CD4041M (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\square$1 <br> 2 <br> 4 |  |  |  | 1. |  | 30 | $\mu \mathrm{A}$ |
|  |  | $0.01$ |  |  |  | 2 |  | 60 | $\mu \mathrm{A}$ |  |
|  |  | $0.01$ |  |  |  | 4 |  | 120 | $\mu \mathrm{A}$ |  |
| VOL | Low Level Output Voltage | $\begin{aligned} & \\| \mathrm{O} \mid<1 \mu \mathrm{~A}, \mathrm{~V}_{I L}=0 \mathrm{~V}, \mathrm{~V}_{I H}=\mathrm{V}_{\mathrm{DD}} \\ & \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{aligned}$ |  |  |  |  |  |  |  |  |
|  |  |  |  | 0.05 | 0 |  | 0.05 |  | 0.05 | v |
|  |  |  |  | 0.05 | 0 |  | 0.05 |  | 0.05 | v |
|  |  |  |  | 0.05 | 0 |  | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $\begin{aligned} & \left\|I_{O}\right\|<1 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{IL}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{IH}}=\mathrm{V}_{\mathrm{DD}} \\ & \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{aligned}$ |  |  |  |  |  |  |  |  |  |
|  |  |  | 4.95 |  | 4.95 |  | 5 |  | 4.95 |  | v |
|  |  |  | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  |  | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| VIL | Low Level Input Voltage | $\|\mathrm{OO}\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.0 |  | 2 | 1.0 |  | 1.0 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V |  | 2.0 |  | 4 | 2.0 |  | 2.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 3.0 |  | 6 | 3.0 |  | 3.0 | v |
| $\mathrm{V}_{1}$ | High Level Input Voltage | $\|\mathrm{OO}\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 4.0 |  | 4.0 | 3 |  | 4.0 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 8.0 |  | 8.0 | 6 |  | 8.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 12.0 |  | 12.0 | 9 |  | 12.0 |  | v |
| $\mathrm{IOL}^{\text {l }}$ | Low Level Output Current True Output | $V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 2.1 |  | 1.6 | 3.2 |  | 1.2 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 6.25 |  | 5.0 | 10 |  | 3.5 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 14 |  | 12 | 24 |  | 8 |  | mA |
| IOL | Low Level Output Current Complement Output | $V_{\text {IH }}=V_{\text {DD }}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.4 \mathrm{~V}$ | 1.0 |  | 0.8 | 1.6 |  | 0.55 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 2.5 |  | 2 | 4.0 |  | 1.4 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ | 5.5 |  | 4.5 | 9.0 |  | 3.0 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current True Output |  |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -1.75 |  | -1.4 | -2.8 |  | -1.0 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -5.0 |  | -4.0 | -8.0 |  | -2.8 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -11 |  | -9 | -18 |  | -6 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current Complement Output | $V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.75 |  | -0.6 | -1.2 |  | -0.4 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -2.25 |  | -1.8 | -3.6 |  | -1.25 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -4.8 |  | -4 | -8 |  | -2.7 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

## DC Electrical Characteristics CD4041C (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\prime \prime} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \\ & \\|_{O I}<1 \mu \mathrm{~A}, V_{I L}=0 \mathrm{~V}, V_{I H}=V_{D D} \\ & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 4 |  | 0.01 | 4 |  | 30 | $\mu \mathrm{A}$ |
|  |  |  |  | 8 |  | 0.01 | 8 |  | 60 | $\mu \mathrm{A}$ |
|  |  | - |  | 16 |  | 0.01 | 16 |  | 120 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage |  |  |  |  |  |  |  |  |  |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| VOH | High Level Output Voltage | $\left\|I_{O}\right\|<1 \mu \mathrm{~A}, \mathrm{~V}_{\text {IL }}=0 \mathrm{~V}, \mathrm{~V}_{1 H}=V_{D D}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL | Low Level Input Voltage | $\left\|\mathrm{IO}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.0 |  | 2 | 1.0 |  | 1.0 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 2.0 |  | 4 | 2.0 |  | 2.0 | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 3.0 |  | 6 | 3.0 |  | 3.0 | V |
| $V_{\text {IH }}$ | High Level Input Voltage | $\left\|I_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 4.0 |  | 4.0 | 3 |  | 4.0 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1 \mathrm{~V}$ or 9 V | 8.0 |  | 8.0 | 6 |  | 8.0 |  | V |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 12.0 |  | 12.0 | 9 |  | 12.0 |  | V |
| ${ }^{\prime} \mathrm{OL}$ | Low Level Output Current True Output | $V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {DD }}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 1.7 |  | 1.5 | 3.2 |  | 1.2 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 4.9 |  | 4.3 | 10 |  | 3.5 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 11 |  | 10 | 24 |  | 8 |  | mA |
| IOL | Low Level Output Current Complement Output | $V_{\text {IH }}=V_{\text {DD }}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V}$ | 0.75 |  | 0.68 | 1.6 |  | 0.55 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 2.0 |  | 1.8 | 4.0 |  | 1.4 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.4 |  | 3.8 | 9.0 |  | 3.0 |  | $m A$ |
| ${ }^{\mathrm{I}} \mathrm{OH}$ | High Level Output Current True Output | $V_{1 H}=V_{D D}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -1.5 |  | $-1.3$ | -2.8 |  | -1.0 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -4.0 |  | -3.5 | -8.0 |  | -2.8 |  | $m A$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=13.5 \mathrm{~V}$ | -8.7 |  | -7.5 | -18 |  | -6 |  | mA |
| IOH | High Level Output Current Complement Output | $V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | -0.57 |  | -0.50 | $-1.2$ |  | -0.4 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.8 |  | -1.6 | -3.6 |  | -1.25 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.9 |  | -3.4 | $-8.0$ |  | -2.7 |  | $m A$ |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | $-1.0$ | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}$, Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}} \stackrel{\circ}{=} 20 \mathrm{~ns}$, unless otherwise specified

| PARAMETER |  | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL or tPLH | Propagation Delay Time True Output | $V_{D D}=5 \mathrm{~V}$ |  | 60 | 120 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 35 | 70 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 25 | 50 | ns |
| tPHL or tPLH | Propagation Delay Time <br> Complement Output | $V_{\text {DD }}=5 \mathrm{~V}$ |  | 75 | 150 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 | 80 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 30 | 65 | ns |
| ${ }^{\text {t }}$ HL or ${ }^{\text {t }}$ LLH | Output Transition Time True Output | $V_{D D}=5 \mathrm{~V}$ |  | 55 | 110 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 30 | 60 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 25 | 50 | ns |
| ${ }^{\text {t }}$ HL or T TLH | Output Transition Time Complement Output | $V_{\text {DD }}=5 \mathrm{~V}$ |  | 90 | 180 | ns |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}$ |  | 45 | 90 | ns |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 35 | 75 | ns |
| CIN | Input Capacitance | Any Input |  | 10 | 15 | pF |



## General Description

The CD4042BM/CD4042BC quad clocked " $D$ " latch is a monolithic complementary MOS (CMOS) integrated circuit constructed with P . and N -channel enhancement mode transistors. The outputs $Q$ and $\bar{Q}$ either latch or follow the data input depending on the clock level which is programmed by the polarity input. For polarity $=0$; the information present at the data input is transferred to $Q$ and $\bar{Q}$ during 0 clock level; and for polarity $=1$, the transfer occurs during the 1 clock level. When a clock transition occurs (positive for polarity $=0$ and negative for polarity $=1$ ), the information present at the input during the clock transition is retained at the outputs until an opposite clock transition occurs.

## Features

- Wide supply voltage range
3.0 V to 15 V
0.45 VDD (typ.)
fan out of 2 driving 74L or 1 driving 74LS
- Low power TTL compatibility
- Clock polarity control
- Fully buffered data inputs
- Q and $\bar{Q}$ outputs


## Connection Diagram

Dual-In-Line and Flat Package


## Truth Table

| CLOCK | POLARITY | $\mathbf{Q}$ |
| :---: | :---: | :---: |
| 0 | 0 | $D$ |
| $\Gamma$ | 0 | Latch |
| 1 | 1 | $D$ |
| $L$ | 1 | Latch |

## Logic Diagrams





Absolute Maximum Ratings
(Notes 1 and 2)
$V_{D D}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
$P_{D}$ Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
-0.5 V to +18 V
-0.5 V to $\mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}$ $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW $300^{\circ} \mathrm{C}$
$V_{D D}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4042BM CD4042BC

3 V to 15 V $O V$ to $V_{D D}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## DC Electrical Characteristics CD4042BM (Note 2)

| PARAMETERS |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 V$ |  | 1 |  | 0.02 | 1 |  | 30 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 2 |  | 0.02 | 2 |  | 60 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 4 |  | 0.02 | 4 |  | 120 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $\left\|\mathrm{I}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}, \mathrm{~V}_{\text {IH }}=\mathrm{V}_{\mathrm{DD}}, \mathrm{V}_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| VOH | High Level Output Voltage | $\left\|I_{O}\right\|<1 \mu A, V_{I H}=V_{D D}, V_{I L}=0 V$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 V$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL | Low Level Input Voltage | $\mathrm{lO} \mathrm{O}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| VIH | High Level Input Voltage | $\|\mathrm{lO}\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  | , |
|  |  | $V_{\text {DD }}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| $\mathrm{IOL}^{\text {I }}$ | Low Level Output Current | $V_{\text {IH }}=V_{\text {DD }}, V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {DD }}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | $\mathrm{mA}$ |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | $\mathrm{mA}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{\text {IH }}=V_{\text {DD }}, V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 | . | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

## DC Electrical Characteristics CD4042BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 4 |  | 0.02 | 4 |  | 30 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 8 |  | 0.02 | 8 |  | 60 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 16 |  | 0.02 | 16 |  | 120 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\\|_{\mathrm{O}} \mid<1 \mu \mathrm{~A}, \mathrm{~V}_{\text {IH }}=\mathrm{V}_{\text {DD }}, V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | $0.05{ }^{\circ}$ |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| VOH | High Level Output Voltage | $\left\|I_{O}\right\|<1 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{IH}}=\mathrm{V}_{\mathrm{DD}}, \mathrm{~V}_{\mathrm{IL}}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL | Low Level Input Voltage | $\|1 \mathrm{O}\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V. |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |

DC Electrical Characteristics (Cont'd.) CD4042BC (Note 2)

| PARAMETER |  | CONDITIONS | -40'c |  | $25^{\prime \prime} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| $V_{\text {IH }}$ | High Level Input Voltage |  | $\mid 10 \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | v |
| IOL | Low Level Output Current | $V_{I H}=V_{D D}, V_{I L}=0 V$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{I H}=V_{D D}, V_{I L}=0 V$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| In | Input Current | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}$, $\operatorname{lnput} \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL, tPLH | Propagation Delay Time Data In to O | $V_{D D}=5 \mathrm{~V}$ |  | 175 | 350 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 75 | 150 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 60 | 120 | ns |
| ${ }^{\text {tPHL }}$ ' ${ }^{\text {P }}$ ( ${ }^{\prime}$ | Propagation Delay Time Data $\ln$ to $\overline{\mathrm{Q}}$ | $V_{D D}=5 \mathrm{~V}$ |  | 150 | 300 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 75 | 150 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 50 | 100 | ns |
| tPHL, tPLH | Propagation Delay Time Clock to Q | $V_{D D}=5 \mathrm{~V}$ |  | 250 | 500 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 | 160 | ns |
| tPHL, tPLH | Propagation Delay Time Clock to $\overline{\mathrm{Q}}$ | $V_{D D}=5 \mathrm{~V}$ |  | 250 | 500 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 115 | 230 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 90 | 180 | ns |
| ${ }^{\text {t }} \mathrm{H}$ | Minimum Hold Time | $V_{D D}=5 \mathrm{~V}$ |  | 60 | 120 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 30 | 60 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 25 | 50 | ns |
| ${ }^{t} \mathrm{SU}$ | Minimum Set-Up Time | $V_{D D}=5 \mathrm{~V}$ |  | 0 | 50 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0 | 30 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0 | 25 | ns |
| tW | Minimum Clock Puise Width | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 30 | 60 | ns |
| tTHL, tTLH | Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 125 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 60 | 125 | ns |
|  | . | $V_{D D}=15 \mathrm{~V}$ |  | 50 | 100 | ns |
| CIN | Input Capacitance | Any Input |  | 5.0 | 7.5 | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: Being a latch, the CD4042BM/CD4042BC is not clock rise and fall time sensitive.
CD4042BM/CD4042BC

## Switching Time Waveforms



## CD4043BM/CD4043BC Quad TRI-STATE ${ }^{\circledR}$ NOR R/S Latches CD4044BM/CD4044BC Quad TRI-STATE ${ }^{\circledR}$ NAND R/S Latches

## General Description

CD4043BM/CD4043BC are quad cross-couple TRI-STATE CMOS NOR latches, and CD4044BM/CD4044BC are quad cross-couple TRI-STATE CMOS NAND latches. Each latch has a separate Q output and individual SET and RESET inputs. There is a common TRI-STATE ENABLE input for all four latches. A logic " 1 " on the ENABLE input connects the latch states to the $Q$ outputs. A logic " 0 " on the ENABLE input disconnects the latch states from the Q outputs resulting in an open circuit condition on the $Q$ output. The TRI-STATE feature allows common bussing of the outputs.

TRI-STATE is a trademark of National Semiconductor Corp.

## Features

$\begin{array}{lr}\text { - Wide supply voltage range } & 3 \mathrm{~V} \text { to } 15 \mathrm{~V} \\ \text { Low power } & 100 \mathrm{nW} \text { (typ.) } \\ \text { - High noise immunity } & 0.45 \mathrm{~V}_{\mathrm{DD}} \text { (typ.) }\end{array}$

- Separate SET and RESET inputs for each latch
- NOR and NAND configuration
- TRI-STATE output with common output enable


## Applications

- Multiple bus storage
- Stobed register
- Four bits of independent storage with output enable
- General digital logic

Schematic and Connection Diagrams
CD4043M/CD4043C


CD4043BM/CD4043BC
Dual-In-Line and Flat Packages


CD4044M/CD4044C


CD4044BM/CD4044BC Dual-In-Line and Flat Packages


## Truth Table

CD4043BM/CD4043BC

| $S$ | $R$ | $E$ | $\mathbf{Q}$ |
| :---: | :---: | :---: | :---: |
| $X$ | $X$ | 0 | $O C$ |
| 0 | 0 | 1 | $N C$ |
| 1 | 0 | 1 | 1 |
| 0 | 1 | 1 | 0 |
| 1 | 1 | 1 | $\Delta$ |

CD4044BM/CD4044BC

| $S$ | $R$ | $E$ | $Q$ |
| :---: | :---: | :---: | :---: |
| $X$ | $X$ | 0 | $O C$ |
| 1 | 1 | 1 | $N C$ |
| 0 | 1 | 1 | 1 |
| 1 | 0 | 1 | 0 |
| 0 | 0 | 1 | $\dot{\Delta}$ |


| Absolute Maximum Ratings |  |
| :--- | ---: |
| (Notes 1 and 2) |  |
| V $_{D D}$ Supply Voltage | -0.5 to +18 V |
| $V_{I N}$ Input Voltage | -0.5 to $V_{D D}+0.5 \mathrm{~V}$ |
| $\mathrm{~T}_{S}$ Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| $\mathrm{P}_{D}$ Package Dissipation | 500 mW |
| $\mathrm{~T}_{\mathrm{L}}$ Lead Temperature (Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ |

Recommended Operating Conditions
(Note 2)
$\begin{array}{lr}V_{D D} \text { Supply Voltage } & 3.0 \text { to } 15 \mathrm{~V} \\ \mathrm{~V}_{\text {IN }} \text { Input Voltage } & 0 \text { to } \mathrm{V}_{D D} \mathrm{~V} \\ \mathrm{~T}_{\mathrm{A}} \text { Operating Temperature Range } & \\ \text { CD4043BM, CD4044BM } & -55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \\ \text { CD4043BC, CD4044BC } & -40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C}\end{array}$

DC Electrical Characteristics CD4043BM/CD4044BM (Note 2)

| Parameter |  | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IDD | Quiescent |  | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  | 5.0 |  | 0.01 | 5.0 |  | 150 | $\mu \mathrm{A}$ |
|  | Device Current | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  | 0.01 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  | 0.02 | 20 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\begin{aligned} & \left\|l_{\mathrm{O}}\right\| \leqslant 1 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{IL}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{IH}}=\mathrm{V}_{\mathrm{DD}} \\ & \mathrm{~V}_{\mathrm{DD}}=5.0 \mathrm{~V} \end{aligned}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\begin{aligned} & \left\|I_{O}\right\| \leqslant 1 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{IL}}=0 \mathrm{~V}, \mathrm{~V}_{I H}=\mathrm{V}_{\mathrm{DD}} \\ & \mathrm{~V}_{\mathrm{DD}}=5.0 \mathrm{~V} \end{aligned}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL | Low Level Input Voltage | $\begin{aligned} & \left\|I_{O}\right\| \leqslant 1 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V} \end{aligned}$ |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High Level Input Voltage | $\begin{aligned} & \left\|I_{\mathrm{O}}\right\| \leqslant 1 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V} \end{aligned}$ | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  |  | $\mathrm{V}_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11 |  | 11 | 8.25 |  | 11 |  | V |
| IOL | Low Level Output Current | $\begin{aligned} & \mathrm{V}_{\mathrm{IL}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{IH}}=\mathrm{V}_{\mathrm{DD}} \\ & \mathrm{~V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V} \end{aligned}$ | 0.64 |  | 0.51 | 1.0 |  | 0.36 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.6 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 6.8 |  | 2.4 |  | mA |
| IOH | High Level | $\mathrm{V}_{\mathrm{IL}}=0 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{H}}=\mathrm{V}_{\mathrm{DD}}$ |  |  |  |  |  |  |  |  |
|  | Output Current | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.25 |  |  |  |  |  |  |  |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -0.62 |  | -0.5 | -1.0 |  | -0.35 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -1.8 |  | -1.5 | -3.0 |  | -1.1 |  | mA |
| In | Input Current | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} -0.1 \\ 0.1 \end{array}$ |  | $\begin{array}{r} -10^{-5} \\ 10^{-5} \end{array}$ | -0.1 0.1 |  | -1.0 1.0 | $\mu \mathrm{A}$ $\mu \mathrm{A}$ |

## DC Electrical Characteristics CD4043BC/CD4044BC (Note 2)

| Parameter |  | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
|  | Quiescent |  | $V_{D D}=5.0 \mathrm{~V}$ |  | 20 |  | 0.01 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  | Device Current | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.01 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 0.02 | 80 |  | 600 | $\mu \mathrm{A}$ |
|  | Low Level Output Voltage | $\begin{aligned} & \left\|I_{\mathrm{O}}\right\| \leqslant 1 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{IL}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{IH}}=\mathrm{V}_{\mathrm{DD}} \\ & \mathrm{~V}_{\mathrm{DD}}=5.0 \mathrm{~V} \end{aligned}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | V $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | High Level Output Voltage | $\begin{aligned} & \left\|l_{\mathrm{O}}\right\| \leqslant 1 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{IL}}=0 \mathrm{~V}, \mathrm{~V}_{I H}=\mathrm{V}_{\mathrm{DD}} \\ & \mathrm{~V}_{\mathrm{DD}}=5.0 \mathrm{~V} \end{aligned}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |

DC Electrical Characteristics CD4043BC/CD4044BC (cont'd)

| Parameter |  | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| VIL | Low Level Input Voltage |  | $\begin{aligned} & \left\|I_{O}\right\| \leqslant 1 \mu \mathrm{~A} \\ & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V} \text { or } 13.5 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ |  | $\begin{gathered} 2.25 \\ 4.5 \\ 6.75 \end{gathered}$ | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ | $\begin{aligned} & V \\ & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\mathrm{IH}}$ | High Level Input Voltage | $\begin{aligned} & \left\|l_{O}\right\| \leqslant 1 \mu \mathrm{~A} \\ & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V} \\ & \mathrm{~V}_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V} \\ & \mathrm{~V}_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V} \text { or } 13.5 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 7.0 \\ & 11 \end{aligned}$ |  | $\begin{aligned} & 3.5 \\ & 7.0 \\ & 11 \end{aligned}$ |  |  | $\begin{aligned} & 3.5 \\ & 7.0 \\ & 11 \end{aligned}$ |  | $\begin{aligned} & V \\ & v \\ & v \end{aligned}$ |
| IOL | Low Level Output Current | $\begin{aligned} & V_{I L}=0 \mathrm{~V}, V_{I H}=V_{D D} \\ & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.4 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 0.52 \\ 1.3 \\ 3.6 \end{gathered}$ |  | 0.44 1.1 3.0 | 0.88 2.2 6.0 |  | 0.36 0.9 2.4 |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \\ & \mathrm{~mA} \end{aligned}$ |
| IOH | High Level Output Current | $\begin{aligned} & \mathrm{V}_{\mathrm{IL}}=0 \mathrm{~V}, \mathrm{~V}_{1 H}=\mathrm{V}_{\mathrm{DD}} \\ & \mathrm{~V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & -0.2 \\ & -0.5 \\ & -1.4 \end{aligned}$ |  | $\begin{gathered} -0.16 \\ -0.4 \\ -1.2 \end{gathered}$ | $\begin{aligned} & -0.32 \\ & -0.8 \\ & -2.4 \end{aligned}$ |  | $\begin{gathered} -0.12 \\ -0.3 \\ -1.0 \end{gathered}$ |  | mA <br> mA <br> mA |
| IN | Input Current | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V} \end{aligned}$ | $\begin{array}{r} -0.3 \\ 0.3 \end{array}$ |  |  | -0.3 0.3 |  |  | -1.0 1.0 | $\mu \mathrm{A}$ |

## AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, R_{L}=200 \mathrm{k}$, Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise noted.



Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $V_{S S}=0 \mathrm{~V}$ unless otherwise specified.


Timing Waveforms


Enable Timing


## CD4046BM/CD4046BC Micropower Phase-Locked Loop

## General Description

The CD4046B micropower phase-locked loop (PLL) consists of a low power, linear, voltage-controlled oscillator (VCO), a source follower, a zener diode, and two phase comparators. The two phase comparators have a common signal input and a common comparator input. The signal input can be directly coupled for a large voltage signal, or capacitively coupled to the self-biasing amplifier at the signal input for a small voltage signal.
Phase comparator $I$, an exclusive OR gate, provides a digital error signal (phase comp. I Out) and maintains $90^{\circ}$ phase shifts at the VCO center frequency. Between signal input and comparator input (both at 50\% duty cycle), it may lock onto the signal input frequencies that are close to harmonics of the VCO center frequency.

Phase comparator II is an edge-controlled digital memory network. It provides a digital error signal (phase comp. II Out) and lock-in signal (phase pulses) to indicate a locked condition and maintains a $0^{\circ}$ phase shift between signal input and comparator input.
The linear voltage-controlled oscillator (VCO) produces an output signal (VCO Out) whose frequency is determined by the voltage at the $\mathrm{VCO}_{\mathbb{I N}}$ input, and the capacitor and resistors connected to pin $\mathrm{C1}_{\mathrm{A}}, \mathrm{C1}_{\mathrm{B}}, \mathrm{R} 1$ and R 2 .
The source follower output of the $\mathrm{VCO}_{\mathbb{I N}}$ (demodulator Out) is used with an external resistor of $10 \mathrm{k} \Omega$ or more.

The INHIBIT input, when high, disables the VCO and source follower to minimize standby power consumption. The zener diode is provided for power supply regulation, if necessary.

## Features

- Wide supply voltage range
3.0 V to 18 V
- Low dynamic power consumption
$70 \mu \mathrm{~W}$ (typ.) at
$\mathrm{f}_{\mathrm{O}}=10 \mathrm{kHz}, \mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$
- VCO frequency
1.3 MHz (typ.) at $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$
- Low frequency drift
$0.06 \% /{ }^{\circ} \mathrm{C}$ at $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ with temperature
- High VCO linearity

1\% (typ.)

## Applications

- FM demodulator and modulator
- Frequency synthesis and multiplication
- Frequency discrimination
- Data synchronization and conditioning
- Voltage-to-frequency conversion
- Tone decoding

FSK modulation

- Motor speed control


## Block and Connection Diagrams



Absolute Maximum Ratings
(Notes 1 and 2)
$V_{D D}$ DC Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{S}}$ Storage Temperature Range $P_{D}$ Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
-0.5 to $+18 \mathrm{~V}_{\mathrm{DC}}$
-0.5 to $V_{D D}+0.5 V_{D C}$ $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW $300^{\circ} \mathrm{C}$

Recommended Operating Conditions
(Note 2)
$V_{D D}$ DC Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4046BM $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ CD4046BC $\quad-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## DC Electrical Characteristics CD4046BM (Note 2)

| Parameter | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Typ | Max | Min | Max |  |
| IDD Quiescent Device Current | PIN $5=V_{D D}$, PIN $14=V_{D D}$, PIN 3, $9=V_{S S}$ |  |  |  |  |  |  |  |  |
|  | $V_{D D}=5 \mathrm{~V}$ |  | 5 |  | 0.005 | 5 |  | 150 | $\mu \mathrm{A}$ |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  | 0.01 | 10 | . | 300 | $\mu \mathrm{A}$ |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  | 0.015 | 20 |  | 600 | $\mu \mathrm{A}$ |
|  | PIN $5=$ VDD, PIN $14=$ Open PIN $3.2=V_{\text {SS }}$ |  |  |  |  |  |  |  |  |
|  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 45 |  | 5 | 35 |  | 185 | $\mu \mathrm{A}$ |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 450 |  | 20 | 350 |  | 650 | $\mu \mathrm{A}$ |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 1200 |  | 50 | 900 |  | 1500 | $\mu \mathrm{A}$ |
| VOL Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| VOH High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL Low Level Input Voltage Comparator and Signal In | $\mathrm{V}_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 |  |  | 1.5 | $v$ |
|  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V} \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | v |
|  | $V_{D D}=15 \mathrm{~V} V_{O}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.25 | 4.0 |  | 4.0 | v |
| $\mathrm{V}_{\mathrm{IH}}$ High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
| Comparator and Signal In | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | v |
| - | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| IOL Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| IOH High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| IIN Input Current | All Inputs Except Signal Input $V_{D D}=14 \mathrm{~V}, V_{I N}=O V$ |  | -0.1 |  | -10-5 | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | 10-5 | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |
| CIN Input Capacitance | Any Input, (Note 3) |  |  |  |  |  |  | 7.5 | pF |
| $\mathrm{P}_{\mathrm{T}}$ Total Power Dissipation | $\begin{aligned} & \mathrm{f}_{\mathrm{O}}=10 \mathrm{kHz}, \mathrm{R} 1=1 \mathrm{M} \Omega \\ & \mathrm{R} 2=\infty, \mathrm{VCO}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{DD}} / 2 \end{aligned}$ |  |  |  |  |  |  |  |  |
|  | $V_{D D}=5 V$ |  |  |  | 0.07 |  |  |  | mW |
|  | $V_{D D}=10 \mathrm{~V}$ |  |  |  | 0.6 |  |  |  | mW |
|  | $V_{D D}=15 \mathrm{~V}$ |  |  |  | 2.4 |  |  |  | mW |

DC Electrical Characteristics CD4046BC (Note 2)

| Parameter | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Typ | Max | Min | Max |  |
| IDD Quiescent Device Current | PIN $5=V_{D D}, \operatorname{PIN} 14=V_{D D}$. PIN $3,9=V_{\text {SS }}$ |  |  |  |  |  |  |  |  |
|  | $V_{D D}=5 \mathrm{~V}$ |  | 20 |  | 0.005 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.01 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 0.015 | 80 |  | 600 | $\mu \mathrm{A}$ |
|  | PIN $5=$ VDD, PIN $14=$ Open, ${ }^{*}$ PIN 3,9 = V SS |  |  |  |  |  |  |  |  |
|  | $V_{D D}=5 \mathrm{~V}$ |  | 70 |  | 5 | 55 |  | 205 | $\mu \mathrm{A}$ |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 530 |  | 20 | 410 |  | 710 | $\mu \mathrm{A}$ |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 1500 |  | 50 | 1200 |  | 1800 | $\mu \mathrm{A}$ |
| VOL Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $V$ |
| VOH High Level Output Voltage | $V_{D D}=5 V$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  | $V_{\text {DD }}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | $\checkmark$ |
| Comparator and Signal In | $V_{D D}=10 \mathrm{~V} V_{O}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.25 | 4.0 |  | 4.0 | V |
| $V_{\text {IH }}$ High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | $3.5$ |  | 3.5 | 2.75 |  | 3.5 |  | V |
| Comparator and Signal In | $V_{D D}=10 \mathrm{~V}, V_{O}=1 \mathrm{~V} \text { or } 9 \mathrm{~V}$ | $7.0$ |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | $1 . .0$ | 8.25 |  | 1.0 |  | $\checkmark$ |
| IOL Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V}$ | $0.52$ |  | 0.44 | 0.88 |  | $0.36$ |  | $\mathrm{mA}$ |
|  | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | $\mathrm{mA}$ |
|  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| 1 OH High Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | $-0.52$ |  | -0.44 | -0.88 |  | $-0.36$ |  | $m A$ |
|  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=13.5 \mathrm{~V}$ | $-3.6$ |  | $-3.0$ | -8.8 |  | $-2.4$ |  | mA |
| IIN Input Current | All Inputs Except Signal Input $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  |  |  | $-10-5$ |  |  |  |  |
|  | $V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V}$ |  | -0.3 |  | -10-5 | $-0.3$ |  | $-1.0$ | $\mu \mathrm{A}$ |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |
| CIN Input Capacitance | Any Input, (Note 3) |  |  |  |  | 7.5 |  |  | pF |
| $\mathrm{P}_{\mathrm{T}}$ Total Power Dissipation | $\begin{aligned} & f_{0}=10 \mathrm{kHz}, R 1=1 \mathrm{MS} 2 \\ & R 2=\infty, V C O_{I N}=V_{D D} / 2 \end{aligned}$ |  |  |  |  |  |  |  |  |
|  | $V_{D D}=5 \mathrm{~V}$ |  |  |  | 0.07 |  |  |  | mW |
|  | $V_{D D}=10 \mathrm{~V}$ |  |  |  | 0.6 |  |  |  | mW |
|  | $V_{D D}=15 \mathrm{~V}$ |  |  |  | 2.4 |  |  |  | mW |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $V_{S S}=O V$ unless otherwise specified.
Note 3: Capacitance is guaranteed by periodic testing.

AC Electrical Characteristics CD4046BM/CD4046BC $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$

| Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| VCO Section |  |  |  |  |  |
| Operating Current IDD | $\begin{aligned} & \mathrm{f}_{\mathrm{O}}=10 \mathrm{kHz}, \mathrm{R1}=1 \mathrm{M} \Omega \\ & \mathrm{R}_{2}=\infty, \mathrm{VCO} I \mathrm{~N}=\mathrm{V}_{\mathrm{DD}} / 2 \\ & \mathrm{VDD}_{\mathrm{DD}}=5 \mathrm{~V} \\ & \mathrm{VDD}_{\mathrm{DD}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 20 \\ & 90 \\ & 200 \end{aligned}$ |  | $\mu \mathrm{A}$ $\mu \mathrm{A}$ $\mu \mathrm{A}$ |
| $\mathrm{f}_{\text {MAX }}=$ Maximum Operating Frequency | $\begin{aligned} & \mathrm{C} 1=50 \mathrm{pF}, 41=10 \mathrm{k} \Omega, \\ & \mathrm{R2} 2=\infty, \mathrm{VCO}, \mathrm{IN}=\mathrm{VDD} \\ & \mathrm{VDD}=5 \mathrm{~V} \\ & \mathrm{VDD}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 0.4 \\ & 0.6 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & 0.8 \\ & 1.2 \\ & 1.6 \end{aligned}$ |  | MHz <br> MHz <br> MHz |
| Linearity | $\begin{aligned} & \mathrm{VCO} I \mathrm{~N}=2.5 \mathrm{~V} \mp 0.3 \mathrm{~V}, \\ & \mathrm{R} 1 \geqslant 10 \mathrm{k} \Omega, \mathrm{VDD}=5 \mathrm{~V} \\ & \mathrm{VCO} / \mathrm{N}=5 \mathrm{~V} \pm 2.5 \mathrm{~V}, \\ & \mathrm{R} 1 \geqslant 400 \mathrm{k} \Omega, \mathrm{VDD}=10 \mathrm{~V} \\ & \mathrm{VCO} \mathrm{~V}=7.5 \mathrm{~V} \pm 5 \mathrm{~V}, \end{aligned}$ |  | $1$ <br> 1 |  | \% <br> \% |
| Temperature-Frequency Stability No Frequency Offset, fMIN = 0 | $\begin{aligned} & \% /{ }^{\circ} \mathrm{C} \propto 1 / \mathrm{f} . \mathrm{VDD} \\ & \mathrm{R} 2=\infty \\ & \mathrm{VDD}=5 \mathrm{~V} \\ & \mathrm{VDD}=10 \mathrm{~V} \\ & \mathrm{VDD}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 0.12-0.24 \\ 0.04-0.08 \\ 0.015-0.03 \end{gathered}$ |  | $\begin{aligned} & \% /{ }^{\circ} \mathrm{C} \\ & \% /{ }^{\circ} \mathrm{C} \\ & \% /{ }^{\circ} \mathrm{C} \end{aligned}$ |
| Frequency Offset, fMIN $\neq 0$ | $\begin{aligned} & V D D=5 \mathrm{~V} \\ & V D D=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 0.06-0.12 \\ 0.05-0.1 \\ 0.03-0.06 \end{gathered}$ |  | $\begin{aligned} & \% /{ }^{\circ} \mathrm{C} \\ & \% /{ }^{\circ} \mathrm{C} \\ & \% /{ }^{\circ} \mathrm{C} \end{aligned}$ |
| VCO IN Input Resistance ( $\mathrm{VCO}_{\mathrm{IN}}$ ) | $\begin{aligned} & V D D=5 \mathrm{~V} \\ & V D D=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 10^{6} \\ & 10^{6} \\ & 10^{6} \end{aligned}$ |  | $\begin{aligned} & M S \Omega \\ & M \Omega \\ & M \Omega \end{aligned}$ |
| VCO Output Duty Cycle | $\begin{aligned} & \mathrm{VDD}=5 \mathrm{~V} \\ & \mathrm{VDD}=10 \mathrm{~V} \\ & \mathrm{~V} D \mathrm{~V}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 50 \\ & 50 \end{aligned}$ |  | $\begin{aligned} & \% \\ & \% \\ & \% \end{aligned}$ |
| tTHL VCO Output Transition Time | $V_{D D}=5 V$ |  | 90 | 200 | ns |
| tTHL | $\begin{aligned} & V D D=10 V \\ & V D D=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 45 \end{aligned}$ | $\begin{aligned} & 100 \\ & 80 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \end{aligned}$ |
| Phase Comparators Section |  |  |  |  |  |
| RIN Input Resistance <br> Signal Input <br> Comparator Input <br> AC-Coupled Signal Input Voltage Sensitivity | $\begin{aligned} & \mathrm{VDD}=5 \mathrm{~V} \\ & \mathrm{VDD}=10 \mathrm{~V} \\ & \mathrm{VDD}=15 \mathrm{~V} \\ & \mathrm{VDD}=5 \mathrm{~V} \\ & \mathrm{VDD}=10 \mathrm{~V} \\ & \mathrm{~V} D \mathrm{~V}=15 \mathrm{~V} \\ & \mathrm{CSERIES}=1000 \mathrm{pF} \\ & \mathrm{C}=50 \mathrm{kHz} \\ & \mathrm{VDD}=5 \mathrm{~V} \\ & \mathrm{~V} D=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \\ & \hline \end{aligned}$ | 1 0.2 0.1 | $\begin{aligned} & 3 \\ & 0.7 \\ & 0.3 \\ & 10^{6} \\ & 10^{6} \\ & 10^{6} \\ & \\ & 200 \\ & 400 \\ & 700 \\ & \hline \end{aligned}$ | $\begin{aligned} & 400 \\ & 800 \\ & 1400 \end{aligned}$ | MS, <br> MS, <br> MS 2 <br> MS <br> MS2 <br> MS <br> mV <br> mV <br> $m V$ |
| Demodulator Output |  |  |  |  |  |
| Offset Voltage (VCO IN | $\begin{aligned} & \mathrm{RS} \geqslant 10 \mathrm{k} \Omega, \mathrm{VDD}=5 \mathrm{~V} \\ & \mathrm{RS} \geqslant 10 \mathrm{k} \Omega, \mathrm{VDD}=10 \mathrm{~V} \\ & \mathrm{RS} \geqslant 50 \mathrm{k} \Omega, \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \\ & \mathrm{RS} \geqslant 50 \mathrm{k} \Omega \\ & \mathrm{VCO} \\ & \mathrm{VCO}=2.5 \pm 0.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V}=5 \pm 2.5 \mathrm{~V}, \mathrm{VD}=10 \mathrm{~V} \\ & \mathrm{VCO} \\ & \mathrm{IN}=7.5 \pm 5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 1.50 \\ & 1.50 \\ & 1.50 \\ & \\ & 0.1 \\ & 0.6 \\ & 0.8 \\ & \hline \end{aligned}$ | $\begin{aligned} & 2.2 \\ & 2.2 \\ & 2.2 \end{aligned}$ | $\begin{aligned} & V \\ & V \\ & V \\ & \% \\ & \% \\ & \% \end{aligned}$ |
| Zener Diode |  |  |  |  |  |
| $V_{Z}$ Zener Diode Voltage $\begin{aligned} & \text { CD4046BM } \\ & \text { CD4046BC } \end{aligned}$ <br> RZ Zener Dynamic Resistance | $\begin{aligned} \mathrm{I} Z & =50 \mu \mathrm{~A} \\ \mathrm{IZ} & =1 \mathrm{~mA} \end{aligned}$ | $\begin{aligned} & 6.7 \\ & 6.3 \end{aligned}$ | $\begin{aligned} & 7.0 \\ & 7.0 \\ & 100 \end{aligned}$ | $\begin{aligned} & 7.3 \\ & 7.7 \end{aligned}$ | $\begin{aligned} & V \\ & V \\ & \Omega \end{aligned}$ |

## Phase Comparator State Diagrams




FIGURE 2

## Typical Waveforms



FIGURE 3. Typical Waveform Employing Phase Comparator 1 in Locked Condition


FIGURE 4. Typical Waveform Employing Phase Comparator II in Locked Condition

Typical Performance Characteristics


Typical VCO Linearity vs R1 and C1



FIGURE 7

Note. To obtain approximate total power dissipation of PLL system for no-signal input: Phase Comparator $I_{,} P_{D}\left(T_{o t a l}\right)=P_{D}\left(f_{O}\right)+P_{D}\left(f_{M I N}\right)+$ $P_{D}\left(R_{S}\right)$; Phase Comparator II, $P_{D}($ Total $)=P_{D}\left(f_{M I N}\right)$.

## Design Information

This information is a guide for approximating the value of external components for the CD4046B in a phase-locked-loop system. The selected external components must be within the following ranges: $\mathrm{R} 1, \mathrm{R} 2 \geq 10 \mathrm{k} \Omega$, $\mathrm{R}_{\mathrm{S}} \geq 10 \mathrm{k} \Omega, \mathrm{C} 1 \geq 50 \mathrm{pF}$.

In addition to the given design information, refer to Figure 5 for R1, R2 and C1 component selections.

| CHARACTERISTICS | USING PHASE COMPARATOR I |  |  | USING PHASE COMPARATOR II |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | O WITHOUT OFFSET $R 2=\infty$ | VCO WITH OFFSET | VCO WITHOUT OFFSET $R 2=\infty$ | VCO WITH OFFSET |
| VCO Frequency | $\begin{aligned} & f_{\text {max }} \\ & \mathrm{t}_{0} \\ & \mathrm{I}_{\text {MIN }} \end{aligned}$ |  |  |  |  |
| For No Signal Input | VCO in PLL system will adjust to center frequency, $f_{0}$ |  |  | VCO in PLL system will adjust to lowest operating frequency, $f_{\text {min }}$ |  |
| Frequency Lock Range, 2 fL | $\begin{aligned} & 2 f_{L}=\text { full } V C O \text { frequency range } \\ & 2 f_{L}=f_{\max }-f_{\min } \end{aligned}$ |  |  |  |  |
| Frequency Capture Range, 2 f C |  |  |  | ${ }^{f} C=f L$ |  |
| Loop Filter Component Selection |  <br> For $2{ }^{f} \mathrm{C}$, see Ref. |  |  |  |  |
| Phase Angle Between Signal and Comparator | $90^{\circ}$ at center frequency ( $f_{0}$ ), approximating $0^{\circ}$ and $180^{\circ}$ at ends of lock range ( 2 fL ) |  |  | Always $0^{\circ}$ in lock |  |
| Locks on Harmonics of Center Frequency | Yes |  |  | No |  |
| Signal Input Noise Rejection | High |  |  | Low |  |
| VCO Component Selection | -Given: $f_{o}$ <br> -Use $f_{0}$ with Figure 5a to determine R1 and C1 |  | -Given: $f_{0}$ and $f_{L}$ <br> -Calculate $f_{\text {min }}$ from the equation $f_{\min }=f_{0}-f_{L}$ <br> -Use $f_{\min }$ with Figure $5 b$ to determine R2 and C1 <br> -Calculate $\frac{f_{\text {max }}}{f_{\text {min }}}$ <br> from the equation $\frac{f_{\max }}{f_{\min }}=\frac{f_{0}+f_{L}}{f_{0}-f_{L}}$ <br> $-U s e_{f_{\min }}^{f_{\text {max }}}$ with Figure $5 c$ to determine ratio R2/ R1 to obtain R1 | -Given: $f_{\text {max }}$ <br> -Calculate $f_{0}$ from the equation $f_{0}=\frac{f_{\max }}{2}$ <br> -Use $f_{0}$ with Figure 5a to determine R1 and C1 | -Given: $f_{\text {min }}$ and $f_{\text {max }}$ <br> -Use $f_{\min }$ with Figure $5 b$ to determine R2 and C1 <br> -Calculate $\frac{f_{\text {max }}}{f_{\text {min }}}$ <br> -Use $\frac{f_{\max }}{f_{\text {min }}}$ with Figure $5 c$ <br> to determine ratıo R2/R1 to obtain R1 |

REF. G.S. Moschytz, "Miniaturized RC Filters Using Phase-Locked Loop", BSTJ, May, 1965.
Floyd Gardner, "Phaselock Techniques," John Wiley \& Sons, 1966.

## CD4047BM/CD4047BC Low Power Monostable/Astable Multivibrator

## General Description

CD4047B is capable of operating in either the monostable or astable mode. It requires an external capacitor (between pins 1 and 3 ) and an external resistor (between pins 2 and 3) to determine the output pulse width in the monostable mode, and the output frequency in the astable mode.

Astable operation is enabled by a high level on the astable input or low level on the astable input. The output frequency (at $50 \%$ duty cycle) at $Q$ and $\bar{Q}$ outputs is determined by the timing components. A frequency twice that of $Q$ is available at the Oscillator Output; a $50 \%$ duty cycle is not guaranteed.
Monostable operation is obtained when the device is triggered by low-to-high transition at + trigger input or high-to-low transition at - trigger input. The device can be retriggered by applying a simultaneous low-to-high transition to both the.+ trigger and retrigger inpuits.

A high level on Reset input resets the outputs $Q$ to low, $\bar{Q}$ to high.

## Features

- Wide supply voltage range
3.0 V to 15 V
- High noise immunity
0.45 VDD (typ.)
- Low power TTL compatibility
fan out of 2 driving 74L or 1 driving 74LS


## SPECIAL FEATURES

- Low power consumption: special CMOS oscillator configuration
- Monostable (one-shot) or astable (free-running) operation
- True and complemented buffered outputs
- Only one external $R$ and $C$ required


## MONOSTABLE MULTIVIBRATOR FEATURES

- Positive- or negative-edge trigger
- Output pulse width independent of trigger pulse duration
- Retriggerable option for pulse width expansion
- Long pulse widths possible using small RC components by means of external counter provision
- Fast recovery time essentially independent of pulse width
- Pulse-width accuracy maintained at duty cycles approaching 100\%


## ASTABLE MULTIVIBRATOR FEATURES

- Free-running or gatable operating modes
- $50 \%$ duty cycle
- Oscillator output available
- Good astable frequency stability
typical $= \pm 2 \%+0.03 \% /{ }^{\circ} \mathrm{C} @ 100 \mathrm{kHz}$
frequency $= \pm 0.5 \%+0.015 \% /{ }^{\circ} \mathrm{C} @ 10 \mathrm{kHz}$
deviation (circuits trimmed to frequency

$$
\left.V_{D D}=10 V \pm 10 \%\right)
$$

## Applications

- Frequency discriminators
- Timing circuits
- Time-delay applications
- Envelope detection
- Frequency multiplication
- Frequency division


## Block and Connection Diagrams



Dual-In-Line and Flat Package

(Notes 1 and 2)
$V_{D D}$ de Supply Voltage
$\mathrm{V}_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
$P_{D}$ Package Dissipation
$\mathrm{T}_{\mathrm{L}}$ Lead Temperature (Soldering, 10 seconds)
-0.5 to $+18 V_{D C}$
-0.5 to $V_{D D}+0.5 V_{D C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW $300^{\circ} \mathrm{C}$
(Note 2)
$V_{\text {DD }}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4047BM CD4047BC

3 to $15 V_{D C}$ 0 to $V_{D D} V_{D C}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## DC Electrical Characteristics CD4047BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 5 |  |  | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  |  | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  |  | 20 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\mid \mathrm{I}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\left\|\mathrm{I}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| $V_{\text {IL }}$ | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | v |
| $V_{1 H}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{0}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | $v$ |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| IN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

DC Electrical Characteristics CD4047BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 20 |  |  | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  |  | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  |  | 80 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $\mid \mathrm{IIO}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |

## DC Electrical Characteristics (Cont'd.) CD4047BC (Note 2)

|  | PARAMETER | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\mid \mathrm{I}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | $v$ |
| $V_{\text {IL }}$ | Low Level Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{\text {IH }}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | $v$ |
| ${ }^{\text {IOL }}$ | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.52 |  | $\bigcirc 0.44$ | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=1.0 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $V_{S S}=O V$ unless otherwise specified.

## AC Electrical Characteristics CD4047B

$T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, R_{L}=200 \mathrm{k}$, Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL, tPLH | Propagation Delay Time Astable, $\overline{\text { Astable to Osc Out }}$ | $V_{D D}=5 \mathrm{~V}$ |  | 200 | 400 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 | 160 | ns |
| tPHL, tPLH | Astable, $\overline{\text { Astable }}$ to $\mathrm{Q}, \overline{\mathrm{Q}}$ | $V_{D D}=5 \mathrm{~V}$ |  | 550 | 900 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 250 | 500 | ns |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 200 | 400 | ns |
| tPHL, tPLH | + Trigger, - Trigger to $\mathrm{Q}, \overline{\mathrm{Q}}$ | $V_{D D}=5 \mathrm{~V}$ |  | 700 | 1200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 300 | 600 | ns |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 240 | 480 | ns |
| tPHL, tPLH | + Trigger, Retrigger to $\mathrm{Q}, \overline{\mathrm{Q}}$ | $V_{\text {DD }}=5 \mathrm{~V}$ |  | 300 | 600 | ns |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}$ |  | 175 | 300 | ns |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 150 | 250 | ns |
| tPHL, tPLH | Reset to $\mathrm{Q}, \overline{\mathrm{Q}}$ | $V_{D D}=5 \mathrm{~V}$ |  | 300 | 600 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 125 | 250 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 100 | 200 | ns |
| ${ }_{\text {t }}^{\text {¢ }} \mathrm{HL}, \mathrm{t}$ TLH | Transition Time Q, $\overline{\mathrm{Q}}, \mathrm{Osc}$ Out | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| ${ }^{\text {tWL, }}$ WH | Minimum Input Pulse Duration | Any Input |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 500 | 1000 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 200 | 400 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 160 | 320 | ns |
| $t_{\text {RCL }},{ }^{\text {t }}$ \%CL | + Trigger, Retrigger, Rise andFall Time | $V_{D D}=5 \mathrm{~V}$ |  |  | 15 | $\mu \mathrm{s}$ |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}$ |  |  | 5 | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  |  | 5 | $\mu \mathrm{s}$ |
| $\mathrm{CIN}^{\text {I }}$ | Average Input Capacitance | Any Input |  | 5 | 7.5 | pF |

## Logic Diagram



## Truth Table

| FUNCTION | TERMINAL CONNECTIONS |  |  | OUTPUT PULSE |
| :--- | :--- | :--- | :--- | :--- | :--- |
|  |  |  |  |  | \(\left.\begin{array}{c}TYPICAL OUTPUT <br>

PERIOD OR <br>
PULSE WIDTH\end{array}\right]\)

Note: External resistor between terminals 2 and 3. External capacitor between terminals 1 and 3.

* Typical Implementation of External Countdown Option



Typical Performance Characteristics


Typical Q, $\overline{\mathbf{Q}}$ and Osc Out
Period Accuracy vs Temperature
Astable Mode Operation


|  | fo, $\overline{\mathbf{Q}}$ | R | C |
| :--- | :--- | :---: | :--- |
| A | 1000 kHz | 22 k | 10 pF |
| B | 100 kHz | 22 k | 100 pF |
| C | 10 kHz | 220 k | 100 pF |
| D | 1 kHz | 220 k | 1000 pF |



Typical $\mathbf{Q}$ and $\overline{\mathbf{Q}}$ Pulse Width
Accuracy vs Temperature Monostable Mode Operation


|  | $\mathbf{t}_{\mathbf{M}}$ | $\mathbf{R}$ | $\mathbf{C}$ |
| :--- | :--- | :---: | :--- |
| A | $2 \mu \mathrm{~s}$ | 22 k | 10 pF |
| B | $7 \mu \mathrm{~s}$ | 22 k | 100 pF |
| C | $60 \mu \mathrm{~s}$ | 220 k | 100 pF |
| D | $550 \mu \mathrm{~s}$ | 220 k | 1000 pF |

## Timing Diágram



## CD4048BM／CD4048BC TRI－STATE ${ }^{\circledR}$ Expandable 8－Function 8－Input Gate

## General Description

The CD4048BM／CD4048BC is a progammable 8 －input gate．Three binary control lines $K_{a}, K_{b}$ ，and $K_{c}$ determine the 8 different logic functions of the gate．These func－ tions are OR，NOR，AND，NAND，OR／AND，OR／NAND， AND／OR，and AND／NOR．A fourth input，$K_{d}$ ，is a TRI－ STATE control．When $K_{d}$ is high，the output is enabled； when $K_{d}$ is low，the output is a high impedance．This feature enables the user to connect the device to a com－ mon bus line．The Expand input permits the user to in－ crease the number of gate inputs．For example，two 8 － input CD4048＇s can be cascaded into a 16 －input multi－ function gate．When the Expand input is not used，it should be connected to $V_{S S}$ ．All inputs are buffered and protected against electrostatic effects．

## Features

－Wide supply voltage range
3.0 V to 15 V
－High noise immunity
－High sink and source current capability
－TTL compatibility
drives 1 standard TTL load at $V_{C C}=5 \mathrm{~V}$ ，
over full temperature range
a Many logic functions in one package

## Logic Diagram



Connection Diagram


## Absolute Maximum Ratings

(Notes 1 and 2)
$V_{\text {DD }}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
PD Package Dissipation
$T_{L}$ Lead Temperature, (Soldering, 10 seconds)
-0.5 V to +18 V
-0.5 V to $\mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW $300^{\circ} \mathrm{C}$
(Note 2)
$V_{D D}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4048BM CD4048BC

3 V to 15 V OV to $V_{D D}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

DC Electrical Characteristics CD4048BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\mathrm{V}_{\text {DD }}=5 \mathrm{~V}$ |  | 5.0 |  | 0.01 | 5.0 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  | 0.01 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  | 0.01 | 20 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{v}_{\mathrm{OL}}$ | Low Level Output Voltage | $\left\|\|O\|<1 \mu \mathrm{~A}, \mathrm{~V}_{1 H}=\mathrm{V}_{\mathrm{DD}}, \mathrm{V}_{\text {IL }}=0 \mathrm{~V}\right.$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $\left\|\mathrm{IO}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}, \mathrm{~V}_{\text {IH }}=\mathrm{V}_{\mathrm{DD}}, \mathrm{V}_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$. | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14:95 |  | v |
| $V_{\text {IL }}$ | Low Level Input Voltage | $\mid \mathrm{lol}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | v |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | v |
| $\mathrm{V}_{\text {IH }}$ | High Level Input Voltage | $\mid \mathrm{IO}_{\mathrm{O}}<1 \mu \mathrm{~A}$ |  |  |  | - |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | v |
| IOL | Low Level Output Current | $V_{\text {IH }}=V_{\text {DD }}, V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 2.8 |  | 2.3 | 4.0 |  | 1.6 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 6.4 |  | 5.2 | 11 |  | 3.6 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 14 |  | 11.5 | 23 |  | 8.0 |  | mA |
| ${ }^{\mathrm{I}} \mathrm{H}$ | High Level Output Current | $V_{\text {IH }}=V_{\text {DD }}, V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -2.8 |  | -2.3 | -4.0 |  | -1.6 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -6.4 |  | -5.2 | -11. |  | -3.6 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -14 |  | -11.5 | -23 |  | -8.0 |  | mA |
| Ioz | TRI-STATE Leakage | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0 \mathrm{~V}$ |  | -0.2 |  | -0.002 | -0.2 |  | -2 | $\mu \mathrm{A}$ |
|  | Current | $V_{D D}=15 \mathrm{~V}, V_{O}=15 \mathrm{~V}$ |  | 0.2 |  | 0.002 | 0.2 |  | 2 | $\mu \mathrm{A}$ |
| IN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

## DC Electrical Characteristics CD4048BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\mathrm{V}_{\text {DD }}=5 \mathrm{~V}$ |  | 20 |  | 0.01 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.01 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 0.01 | 80 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\|\mathrm{IO}\|<1 \mu \mathrm{~A}, \mathrm{~V}_{\text {IH }} \doteq \mathrm{V}_{\mathrm{DD}}, \mathrm{V}_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |

DC Electrical Characteristics (Cont'd.) CD4048BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| VOH | High Level Output Voltage |  | $\\| \mathrm{O} \mid<1 \mu \mathrm{~A}, \mathrm{~V}_{\text {IH }}=\mathrm{V}_{\text {DD }}, \mathrm{V}_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL | Low Level Input Voltage | $\left\|\mathrm{IO}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{O}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $V_{\text {IH }}$ | High Level Input Voltage | $\|\mathrm{IO}\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| IOL | Low Level Output Current | $V_{\text {IH }}=V_{\text {DD }}, V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V}$ | 2.3 |  | 2.0 | 4.0 |  |  | 1.6 | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ | 5.2 |  | 4.5 | 11 |  |  | 3.6 | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 11.5 |  | 9.8 | 23 |  |  | 8.0 | mA |
| $\mathrm{IOH}^{\prime}$ | High Level Output Current | $V_{\text {IH }}=V_{\text {DD }}, V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -2.3 |  | -2.0 | -4.0 |  |  | -1.6 | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -5.2 |  | -4.5 | -11 |  |  | -3.6 | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -11.5 |  | -9.8 | -23 |  |  | -8.0 | mA |
| ITL | TRI-STATE Leakage | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0 \mathrm{~V}$ |  | -0.6 |  | -0.005 | -0.6 |  | -2 | $\mu \mathrm{A}$ |
|  | Current | $V_{D D}=15 \mathrm{~V}, V_{O}=15 \mathrm{~V}$ |  | 0.6 |  | 0.005 | 0.6 |  | 2 | $\mu \mathrm{A}$ |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k} \Omega$, and $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL, tPLH | Propagation Delay Time | $V_{D D}=5 V$ |  | 425 | 850 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 200 | 400 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 160 | 320 | ns |
| tPLZ, tPHZ | Propagation Delay Time, $\mathrm{K}_{\mathrm{d}}$ to | $\mathrm{R}_{\mathrm{L}}=1.0 \mathrm{k} \Omega$ |  |  |  |  |
|  | High Impedance (From Active | $V_{D D}=5 \mathrm{~V}$ |  | 175 | 350 | ns |
|  | Low or High Level) | $V_{D D}=10 \mathrm{~V}$ |  | 125 | 250 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 100 | 200 | ns |
| tPZL, tPZH | Propagation Delay Time, $\mathrm{K}_{\mathrm{d}}$ to | $\mathrm{R}_{\mathrm{L}}=1.0 \mathrm{k} \Omega$ |  |  |  |  |
|  | Active High or Low Level | $V_{D D}=5 \mathrm{~V}$ |  | 225 | 450 | ns |
|  | (From High Impedance) | $V V_{D D}=10 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 70 | 140 | ns |
| ${ }^{\text {t }}$ HL, ${ }^{\text {t }}$ L H | Output Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| CIN | Input Capacitance | Any Input |  | 5 | 7.5 | pF |
| COUT | Tristate output |  |  |  |  |  |
|  | Capacitance |  |  |  | 22.5 | pF |

## Truth Table

| OUTPUT <br> FUNCTION | BOOLEAN EXPRESSION | CONTROL INPUTS |  |  |  | UNUSED INPUTS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{K}_{\mathrm{a}}$ | $\mathbf{K}_{\mathbf{b}}$ | $\mathrm{K}_{\mathrm{c}}$ | $\mathrm{K}_{\mathbf{d}}$ |  |
| NOR | $J=\overline{A+B+C+D+E+F+G+H}$ | 0 | 0 | 0 | 1 | $V_{\text {SS }}$ |
| OR | $J=A+B+C+D+E+F+G+H$ | 0 | 0 | 1 | 1 | $V_{\text {SS }}$ |
| OR/AND | $J=(A+B+C+D) \cdot(E+F+G+H)$ | 0 | 1 | 0 | 1 | $V_{\text {SS }}$ |
| OR/NAND | $J=\overline{(A+B+C+D) \cdot(E+F+G+H)}$ | 0 | 1 | 1 | 1 | $V_{\text {SS }}$ |
| AND | $J=A \cdot B \cdot C \cdot D \cdot E \cdot F \cdot G \cdot H$ | 1 | 0 | 0 | 1 | $V_{\text {DD }}$ |
| NAND | $J=\overline{A \cdot B \cdot C \cdot D \cdot E \cdot F \cdot G \cdot H}$ | 1 | 0 | 1 | 1 | $V_{\text {DD }}$ |
| AND/NOR | $J=\overline{(A \cdot B \cdot C \cdot D)+(E \cdot F \cdot G \cdot H)}$ | 1 | 1 | 0 | 1 | $V_{\text {DD }}$ |
| AND/OR | $J=(A \cdot B \cdot C \cdot D)+(E \cdot F \cdot G \cdot H)$ | 1 | 1 | 1 | 1 | $V_{\text {DD }}$ |
| $\mathrm{Hi}-\mathrm{Z}$ |  | X | X | X | 0 | X |

Positive logic: $0=$ low level, $1=$ high level, $X=$ irrelevant, EXPAND input tied to $V_{\text {SS }}$.

## AC Test Circuits and Switching Time Waveforms

Logic Propagation Delay Time Tests


TRI-STATE Propagation Delay Time Tests


## Typical Performance Characteristics



## Basic Logic Configurations



## Actual Circuit Configurations


$K_{a} K_{b} K_{c}=000$

AND

$=100$

$=001$

OR／AND


$=101$

$=110$


$$
=110
$$


$=111$

Truth Table for EXPAND Feature

| COMBINED <br> OUTPUT <br> FUNCTION | FUNCTION <br> NEEDED AT <br> EXPAND INPUT | OUTPUT BOOLEAN <br> EXPRESSION |
| :--- | :---: | :---: |
| NOR | OR | $\mathrm{J}=\overline{(A+B+C+D+E+F+G+H)+(E X P)}$ |
| OR | OR | $\mathrm{J}=(\mathrm{A}+\mathrm{B}+\mathrm{C}+\mathrm{D}+\mathrm{E}+\mathrm{F}+\mathrm{G}+\mathrm{H})+(E X P)$ |
| AND | NAND | $\mathrm{J}=(\mathrm{ABCDEFGH}) \cdot(\overline{E X P})$ |
| NAND | NAND | $\mathrm{J}=(\mathrm{ABCDEFGH}) \cdot(E X P)$ |
| OR/AND | NOR | $\mathrm{J}=(\mathrm{A}+\mathrm{B}+\mathrm{C}+\mathrm{D}) \cdot(E+\mathrm{F}+\mathrm{G}+\mathrm{H}) \cdot(\overline{E X P})$ |
| OR/NAND | NOR | $\mathrm{J}=(\mathrm{A}+\mathrm{B}+\mathrm{C}+\mathrm{D}) \cdot(E+\mathrm{F}+\mathrm{G}+\mathrm{H}) \cdot(E X P)$ |
| AND/NOR | AND | $\mathrm{J}=(\mathrm{ABCD})+(E F G H)+(E X P)$ |
| AND/OR | AND | $\mathrm{J}=(A B C D)+(E F G H)+(E X P)$ |

Note. Positive logic is assumed. (EXP) represents the logic level present at the EXPAND input.

## Typical Applications of EXPAND Feature



## General Description

These hex buffers are monolithic complementary MOS (CMOS) integrated circuits constructed with N - and P channel enhancement mode transistors. These devices feature logic level conversion using only one supply voltage ( $\mathrm{V}_{\mathrm{DD}}$ ). The input signal high level $\left(\mathrm{V}_{\mathrm{IH}}\right)$ can exceed the $V_{D D}$ supply voltage when these devices are used for logic level conversions. These devices are intended for use as hex buffers, CMOS to DTL/TTL converters, or as CMOS current drivers, and at $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$, they can drive directly two DTL/TTL loads over the full operating temperature range.

## Features

- Wide supply voltage range
3.0 V to 15 V
- Direct drive to 2 TTL loads at 5.0 V over full temperature range
- High source and sink current capability
- Special input protection permits input voltages greater than $V_{D D}$


## Applications

- CMOS hex inverter/buffer
- CMOS to DTL/TTL hex converter
- CMOS current "sink" or "source" driver
- CMOS high-to-low logic level converter


## Connection Diagrams



CD4050BM/CD4050BC Dual-In-Line and Flat Packago


## Schematic Diagrams



Absolute Maximum Ratings
(Notes 1 and 2)
VDD Supply Voltage
$V_{\text {IN }}$ Input Voltage
VOUT Voltage at Any Output Pin
TS Storage Temperature Range
$P_{D}$ Package Dissipation
$T_{L}$ ©Lead Temperature (Soldering, 10 seconds)
-0.5 V to +18 V
-0.5 V to +18 V
-0.5 V to $\mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW
$300^{\circ} \mathrm{C}$
(Note 2)
$V_{D D}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
VOUT Voltage at Any Output Pin
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range $\begin{array}{lr}\text { CD4049M, CD4050BM } & -55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \\ \text { CD4049C, CD4050BC } & -40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C}\end{array}$

DC Electrical Characteristics CD4049M/CD4050BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 V \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \\ & V_{I H}=V_{D D}, V_{I L}=0, \\ & I_{O} \mid<1 \mu \mathrm{~A} \\ & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 1.0 |  | 0.01 | 1.0 |  | 30 | $\mu \mathrm{A}$ |
|  |  |  |  | 2.0 |  | 0.01 | 2.0 |  | 60 | $\mu \mathrm{A}$ |
|  |  |  |  | 4.0 |  | 0.03 | 4.0 |  | 120 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage |  |  |  |  |  |  |  |  |  |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\begin{aligned} & V_{I H}=V_{D D}, V_{I L}=0, \\ & I_{O} \mid<1 \mu \mathrm{~A} \end{aligned}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | L.ow Level Input Voltage (CD4050BM Only) | $\\|_{0} \mid<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.5 \mathrm{~V}$ |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $V_{\text {IL }}$ | Low Level Input Voltage (CD4049M Only) | $\|1 \mathrm{O}\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.5 \mathrm{~V}$ |  | 1.0 |  | 1.5 | 1.0 |  | 1.0 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9 \mathrm{~V}$ |  | 2.0 |  | 2.5 | 2.0 |  | 2.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=13.5 \mathrm{~V}$ |  | 3.0 |  | 3.5 | 3.0 |  | 3.0 | V |
| VIH | High Level Input Voltage (CD4050BM Only) | $\\|_{0} \mathrm{O}<1<\mathrm{A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.5 \mathrm{~V}$ |  |  | 3.5 | 2.75 |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9 \mathrm{~V}$ | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| $\mathrm{V}_{1} \mathrm{H}$ | High Level Input Voltage (CD4049M Only) | $\\|_{0} \mid<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.5 \mathrm{~V}$ | 4.0 |  | 4.0 | 3.5 |  | 4.0 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ | 8.0 |  | 8.0 | 7.5 |  | 8.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 12.0 |  | 12.0 | 11.5 |  | 12.0 |  | V |
| IOL | Low Level Output Current (Note 3) | $V_{I H}=V_{D D}, V_{I L}=0 V$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 5.6 |  | 4.6 | 5 |  | 3.2 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 12 |  | 9.8 | 12 |  | 6.8 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 35 |  | 29 | 40 |  | 20 |  | mA |
| ${ }^{\mathrm{OH}}$ | High Level Output Current (Note 3) |  |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -1.3 |  | -1.1 | $-1.6$ |  | -0.72 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -2.6 |  | -2.2 | -3.6 |  | -1.5 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -8.0 |  | $-7.2$ | -12 |  | $-5.0$ |  | mA |
| IN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: These are peak output current capabilities. Continuous output current is rated at 12 mA maximum. The output current should not be allowed to exceed this value for extended periods of time.

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\prime \prime} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \\ & V_{I H}=V_{D D}, V_{I L}=0 \mathrm{~V}, \\ & I_{O} \mid<1 \mu \mathrm{~A} \\ & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 4 |  | 0.03 | 4.0 |  | 30 | $\mu \mathrm{A}$ |
|  |  |  |  | 8 |  | 0.05 | 8.0 |  | 60 | $\mu \mathrm{A}$ |
|  |  |  |  | 16 |  | 0.07 | 16.0 |  | 120 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage |  |  |  |  |  |  |  |  |  |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\begin{aligned} & V_{I H}=V_{D D}, V_{I L}=0 V \\ & \\|_{O} /<1 \mu A \end{aligned}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| $V_{\text {IL }}$ | Low Level Input Voltage (CD4050BC Only) | $\mid \mathrm{I}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1 \mathrm{~V}$ |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | v |
| $V_{\text {IL }}$ | Low Level Input Voltage (CD4049C Only) | $\left\|\\|_{0}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.5 \mathrm{~V}$ |  | 1.0 |  | 1.5 | 1.0 |  | 1.0 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9 \mathrm{~V}$ |  | 2.0 |  | 2.5 | 2.0 |  | 2.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ |  | 3.0 |  | 3.5 | 3.0 |  | 3.0 | V |
| $V_{\text {IH }}$ | High Level Input Voltage (CD4050BC Only) | $\\|_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.5 \mathrm{~V}$ | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9 \mathrm{~V}$ | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| $\mathrm{V}_{\text {IH }}$ | High Level Input Voltage (CD4049C Only) | $\left\|{ }^{0} \mathrm{O}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ | 4.0 |  | 4.0 | 3.5 |  | 4.0 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ | 8.0 |  | 8.0 | 7.5 |  | 8.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 12.0 |  | 12.0 | 11.5 |  | 12.0 |  | v |
| IOL | Low Level Output Current (Note 3) | $V_{\text {IH }}=V_{\text {DD }}, V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V}$ | 4.6 |  | 4.0 | 5 |  | 3.2 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ | 9.8 |  | 8.5 | 12 |  | 6.8 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ | 29 |  | 25 | 40 |  | 20 |  | mA |
| ${ }^{\mathrm{IOH}}$ | High Level Output Current (Note 3) | $V_{I H}=v_{D D}, V_{I L}=0 V$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ |  |  |  |  |  | $-0.72$ |  | mA |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -2.1 |  | -1.9 | -3.6 |  | -1.5 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -7.1 |  | -6.2 | -12 |  | -5 | - | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ | -0.3 |  | -0.3 | $-10^{-5}$ |  |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ | 0.3 |  | 0.3 | $10^{-5}$ |  |  | 1.0 | $\mu \mathrm{A}$ |

## AC Electrical Characteristics cD4049M/CD4049C

$T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified.

|  | - PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL | Propagation Delay Time High-to-Low Level | $V_{D D}=5 \mathrm{~V}$ |  | 30 | 65 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 20 | 40 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 15 | 30 | ns |
| tPLH | Propagation Delay Time Low-to-High Level | $V_{D D}=5 \mathrm{~V}$ |  | 45 | 85 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 25 | 45 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 | 35 | ns |
| tTHL | Transition Time High-to-Low Level | $V_{D D}=5 \mathrm{~V}$ |  | 30 | 60 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 20 | 40 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 15 | 30 | ns |
| tTLH | Transition Time Low-to-High Level | $V_{D D}=5 \mathrm{~V}$ |  | 60 | 120 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 30 | 55 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 25 | 45 | ns |
| $\mathrm{CIN}^{\text {I }}$ | Input Cảpacitance | Any Input |  | 15 | 22.5 | pF |

## AC Electrical Characteristics CD4050вm/CD4050BC

$T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, R_{L}=200 \mathrm{k}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified.

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |  |
| :--- | :--- | :---: | :---: | :---: | :---: | :---: |
| tPHL | Propagation Delay Time High-to-Low Level | $V_{D D}=5 \mathrm{~V}$ |  | 60 | 110 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 25 | 55 | ns |
| tPLH | Propagation Delay Time Low-to-High Level | $V_{D D}=15 \mathrm{~V}$ |  | 20 | 30 | ns |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 60 | 120 | ns |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 30 | 55 | ns |  |
| tTHL | Transition Time High-to-Low Level | $V_{D D}=15 \mathrm{~V}$ |  | 25 | 45 | ns |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 30 | 60 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 20 | 40 | ns |
| tTLH | Transition Time Low-to-High Level | $V_{D D}=15 \mathrm{~V}$ |  | 15 | 30 | ns |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 60 | 120 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 30 | 55 | ns |
| CIN | Input Capacitance | $V_{D D}=15 \mathrm{~V}$ |  | 25 | 45 | ns |

## Switching Time Waveforms



## Typical Applications

CMOS to TTL or CMOS at a Lower VDD


## Note: $V_{D D 1} \geq V_{D D 2}$

Note: In the case of the CD4049M/CD4049C
the output drive capability increases with increasing input voltage. E.g., If $V_{D D}{ }^{=}=10 \mathrm{~V}$ the $C D 4049 \mathrm{M} /$ CD4049C could drive 4 TTL loads.

# CD4051BM/CD4051BC Single 8-Channel Analog Multiplexer/Demultiplexer CD4052BM/CD4052BC Dual 4-Channel Analog Multiplexer/Demultiplexer CD4053BM/CD4053BC Triple 2-Channel Analog Multiplexer/Demultiplexer 

## General Description

These analog multiplexers/demultiplexers are digitally controlled analog switches having low "ON" impedance and very low "OFF" leakage currents. Control of analog signals up to $15 \mathrm{~V}_{\mathrm{p}-\mathrm{p}}$ can be achieved by digital signal amplitudes of $3-15 \mathrm{~V}$. For example, if $\mathrm{V}_{D D}=5 \mathrm{~V}, \mathrm{~V}_{S S}=0 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{EE}}=-5 \mathrm{~V}$, analog signals from -5 V to +5 V can be controlled by digital inputs of $0-5 \mathrm{~V}$. The multiplexer circuits dissipate extremely low quiescent power over the full $V_{D D}-V_{S S}$ and $V_{D D}-V_{E E}$ supply voltage ranges, independent of the logic state of the control signals. When a logical " 1 " is present at the inhibit input terminal all channels are "OFF".
CD4051BM/CD4051BC is a single 8-channel multiplexer having three binary control inputs. A, B, and C, and an inhibit input. The three binary signals select 1 of 8 channels to be turned "ON" and connect the input to the output.

CD4052BM/CD4052BC is a differential 4-channel multiplexer having two binary control inputs, A and B , and an inhibit input. The two binary input signals select 1 or 4 pairs of channels to be turned on and connect the differential analog inputs to the differential outputs.
CD4053BM/CD4053BC is a triple 2-channel multiplexer having three separate digital control inputs, $A, B$, and $C$, and an inhibit input. Each control input selects one of a pair of channels which are connected in a single-pole double-throw configuration.

## Features

- Wide range of digital and analog signal levels: digital $3-15 \mathrm{~V}$, analog to $15 \mathrm{~V}_{\mathrm{p}-\mathrm{p}}$
- Low "ON" resistance: $80 \Omega$ (typ.) over entire $15 \mathrm{~V}_{\mathrm{p}-\mathrm{p}}$ signal-input range for $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{EE}}=15 \mathrm{~V}$

■ High "OFF" resistance: channel leakage of $\pm 10 \mathrm{pA}$ (typ.) at $V_{D D}-V_{E E}=10 \mathrm{~V}$

- Logic level conversion for digital addressing signals of $3-15 \mathrm{~V}\left(\mathrm{~V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=3-15 \mathrm{~V}\right)$ to switch analog signals to $15 \mathrm{~V}_{\mathrm{p}-\mathrm{p}}\left(\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{EE}}=15 \mathrm{~V}\right)$
- Matched switch characteristics: $\Delta R_{O N}=5 \Omega$ (typ.) for $V_{D D}-V_{E E}=15 \mathrm{~V}$
- Very low quiescent power dissipation under all digitalcontrol input and supply conditions: $1 \mu \mathrm{~W}$ (typ.) at $V_{D D}-V_{S S}=V_{D D}-V_{E E}=10 V$
- Binary address decoding on chip


## Connection Diagrams



CD4052BM/CD4052BC


CD4053BM/CD4053BC


## Absolute Maximum Ratings

| $V_{D D}$ | DC Supply Voltage | -0.5 Vdc to +18 Vdc |
| :--- | :--- | ---: |
| $\mathrm{V}_{\text {IN }}$ | Input Voltage | -0.5 Vdc to $\mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{Vdc}$ |
| $\mathrm{T}_{\mathrm{S}}$ | Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| $\mathrm{P}_{\mathrm{D}}$ | Package Dissipation | 500 mW |
| $\mathrm{~T}_{\mathrm{L}}$ | Lead Temperature (soldering, | 10 seconds) |
|  | $300^{\circ} \mathrm{C}$ |  |

## DC Electrical Characteristics (Note 2)

\begin{tabular}{|c|c|c|c|c|c|c|c|c|c|c|c|}
\hline \& \multirow[b]{2}{*}{Parameter} \& \multicolumn{2}{|r|}{\multirow[b]{2}{*}{Conditions}} \& \multicolumn{3}{|c|}{\(-55^{\circ} \mathrm{C}\)} \& \multicolumn{2}{|l|}{\(+25^{\circ} \mathrm{C} \quad+\)} \& \multicolumn{2}{|l|}{\(+125^{\circ} \mathrm{C}\)} \& \multirow[b]{2}{*}{Units} \\
\hline \& \& \& \& Min \& Max \& Min \& Typ \& Max \& Min \& Max \& \\
\hline IDD \& Quiescent Device Current \& \[
\begin{aligned}
\& V_{D D}=5 \mathrm{~V} \\
\& V_{D D}=10 \mathrm{~V} \\
\& V_{D D}=15 \mathrm{~V}
\end{aligned}
\] \& \& \& \[
\begin{aligned}
\& 5 \\
\& 10 \\
\& 20
\end{aligned}
\] \& \& \& 5
20
20 \& \& \[
\begin{aligned}
\& 150 \\
\& 600 \\
\& 600
\end{aligned}
\] \& \[
\begin{aligned}
\& \mu \mathrm{A} \\
\& \mu \mathrm{~A} \\
\& \mu \mathrm{~A}
\end{aligned}
\] \\
\hline \multicolumn{12}{|l|}{Signal Inputs ( \(\mathrm{V}_{\text {IS }}\) ) and Outputs ( \(\mathrm{V}_{\text {OS }}\) )} \\
\hline RON \& "ON" Resistance (Peak for \(V_{E E} \leqslant V_{I S} \leqslant V_{D D}\) ) \& \[
\begin{aligned}
\& R_{\mathrm{L}}=10 \mathrm{k} \Omega \\
\& \text { (any channel } \\
\& \text { selected) }
\end{aligned}
\] \& \[
\begin{aligned}
\& V_{D D}=2.5 \mathrm{~V}, \\
\& V_{E E}=-2.5 \mathrm{~V} \\
\& \text { or } V_{D D}=5 \mathrm{~V}, \\
\& V_{E E}=0 \mathrm{~V} \\
\& \hline V_{D D}=5 \mathrm{~V} \\
\& V_{E E}=-5 \mathrm{~V} \\
\& \text { or } V_{D D}=10 \mathrm{~V}, \\
\& V_{E E}=0 \mathrm{~V} \\
\& \mathrm{~V}_{\mathrm{DD}}=7.5 \mathrm{~V}, \\
\& \mathrm{~V}_{\mathrm{EE}}=-7.5 \mathrm{~V} \\
\& \text { or } \mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \\
\& \mathrm{~V}_{\mathrm{EE}}=0 \mathrm{~V}
\end{aligned}
\] \& \& \[
\begin{aligned}
\& 2000 \\
\& 310 \\
\& 220
\end{aligned}
\] \& \& \begin{tabular}{l}
270 \\
120 \\
80
\end{tabular} \& \begin{tabular}{l}
2500 \\
400
\[
280
\]
\end{tabular} \& \& \begin{tabular}{l}
3500 \\
580 \\
400
\end{tabular} \& \begin{tabular}{l}
\(\Omega\) \\
\\
\\
\\
\hline
\end{tabular} \\
\hline \multirow[t]{2}{*}{\(\triangle \mathrm{R}_{\text {ON }}\)} \& \(\triangle\) "ON" Resistance Between Any Two Channels \& \[
\begin{aligned}
\& \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega \\
\& \text { (any channel } \\
\& \text { selected) }
\end{aligned}
\] \& \[
\begin{aligned}
\& \mathrm{V} D \mathrm{DD}=2.5 \mathrm{~V}, \\
\& \mathrm{~V}_{\mathrm{EE}}=-2.5 \mathrm{~V} \\
\& \text { or } V_{D D}=5 \mathrm{~V}, \\
\& \mathrm{~V}_{\mathrm{EE}}=0 \mathrm{~V} \\
\& \hline \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V}, \\
\& \mathrm{VEE}=-5 \mathrm{~V} \\
\& \text { or } \mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V} \text {, } \\
\& \mathrm{V}_{\mathrm{EE}}=0 \mathrm{~V} \\
\& \hline \mathrm{~V}_{\mathrm{DD}}=7.5 \mathrm{~V}, \\
\& \mathrm{VEE}_{\mathrm{EE}}=-7.5 \mathrm{~V} \\
\& \text { or } \mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \\
\& \mathrm{~V}_{\mathrm{EE}}=0 \mathrm{~V}
\end{aligned}
\] \& \& \& \& \begin{tabular}{l}
10 \\
10 \\
5
\end{tabular} \& \& \& \& \(\Omega\)

$\Omega$ <br>

\hline \& | "OFF" Channel Leakage Current, any channel "OFF" |
| :--- |
| "OFF" Channel Leakage Current, all channels "OFF" (Common OUT/IN) | \& \multicolumn{2}{|l|}{\[

$$
\begin{array}{ll}
\text { Inhibit }=7.5 \mathrm{~V} & \text { CD4051 } \\
\mathrm{VDD}=7.5 \mathrm{~V}, & \\
\mathrm{VEE}=-7.5 \mathrm{~V}, & \mathrm{CD} 4052 \\
\mathrm{O} / \mathrm{I}=0 \mathrm{~V}, & \\
\mathrm{I} / \mathrm{O}= \pm 7.5 \mathrm{~V} & \mathrm{CD} 4053
\end{array}
$$

\]} \& \& \[

$$
\begin{aligned}
& \pm 50 \\
& \pm 200 \\
& \pm 200 \\
& \pm 200 \\
& \hline
\end{aligned}
$$

\] \& \& \[

$$
\begin{aligned}
& \pm 0.01 \\
& \pm 0.08 \\
& \pm 0.04 \\
& \pm 0.02
\end{aligned}
$$

\] \& \[

$$
\begin{aligned}
& \pm 50 \\
& \pm 200 \\
& \pm 200 \\
& \pm 200
\end{aligned}
$$

\] \& \& \[

$$
\begin{aligned}
& \pm 500 \\
& \pm 2000 \\
& \pm 2000 \\
& \pm 2000
\end{aligned}
$$

\] \& | nA |
| :--- |
| nA |
| nA |
| nA | <br>

\hline
\end{tabular}

Control Inputs A, B, C and Inhibit

| VIL | Low Level Input Voltage | $V_{E E}=V_{S S} R_{L}=1 \mathrm{k} \Omega$ to $V_{S S}$ IIS $<2 \mu \mathrm{~A}$ on all OFF channels $V_{\text {IS }}=V_{D D}$ thru $1 k \Omega$ <br> $V_{D D}=5 V$ <br> $V_{D D}=10 \mathrm{~V}$ <br> $V_{D D}=15 \mathrm{~V}$ |  | 1.5 3.0 4.0 |  |  | 1.5 3.0 4.0 |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ | V V V |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {IH }}$ | High Level Input Voltage | $\begin{aligned} & V_{D D}=5 \\ & V_{D D}=10 \\ & V_{D D}=15 \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 7 \\ & 11 \end{aligned}$ |  | $\begin{aligned} & 3.5 \\ & 7 \\ & 11 \end{aligned}$ |  |  | $\begin{aligned} & 3.5 \\ & 7 \\ & 11 \end{aligned}$ |  | V V V |
| IIN | Input Current | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, V_{E E}=0 \mathrm{~V} \\ & V_{I N}=0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, \\ & V_{I N}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} -0.1 \\ 0.1 \end{array}$ |  | $\begin{array}{r} -10^{-5} \\ 10^{-5} \end{array}$ | $\begin{array}{r} -0.1 \\ 0.1 \end{array}$ |  | $\begin{array}{r} -1.0 \\ 1.0 \end{array}$ | $\mu \mathrm{A}$ $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: All voltages measured with respect to $V_{\text {SS }}$ unless otherwise specified.

Recommended Operating Conditions
$V_{D D}$ DC Supply Voltage
+5 Vdc to +15 Vdc $0 V$ to $V_{D D} V d c$
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range 4051BM/4052BM/4053BM $4051 \mathrm{BC} / 4052 \mathrm{BC} / 4053 \mathrm{BC}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

DC Electrical Characteristics (Cont'd.) (Note 2)


Note 1: "Absolute Maximum Ratings' are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: All voltages measured with respect to $V_{S S}$ unless otherwise specified.

## AC Electrical Characteristics

$T_{A}=25^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified.

| Parameter |  | Conditions | $\mathrm{V}_{\mathrm{pp}}$ | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPZH, tPZL | Propagation Delay Time from Inhibit to Signal Output (channel turning on) | $\begin{aligned} & V_{E E}=V_{S S}=0 \mathrm{~V} \\ & R_{L}=1 \mathrm{k} \Omega \\ & C_{L}=50 \mathrm{pF} \end{aligned}$ | $\begin{array}{r} 5 \mathrm{~V} \\ 10 \mathrm{~V} \\ 15 \mathrm{~V} \end{array}$ |  | $\begin{aligned} & 600 \\ & 225 \\ & 160 \end{aligned}$ | $\begin{aligned} & 1200 \\ & 450 \\ & 320 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\begin{aligned} & \text { tPHZ } \\ & \text { tpLZ } \end{aligned}$ | Propagation Delay Time from Inhibit to Signal Output (channel turning off) | $\begin{aligned} & V_{E E}=V_{S S}=0 V \\ & R_{L}=1 \mathrm{k} \Omega \\ & C_{L}=50 \mathrm{pF} \end{aligned}$ | $\begin{array}{r} 5 \mathrm{~V} \\ 10 \mathrm{~V} \\ 15 \mathrm{~V} \end{array}$ |  | $\begin{aligned} & 210 \\ & 100 \\ & 75 \end{aligned}$ | $\begin{aligned} & 420 \\ & 200 \\ & 150 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| CIN | Input Capacitance Control Input Signal Input (IN/OUT) |  |  |  | $\begin{aligned} & 5 \\ & 10 \end{aligned}$ | $\begin{aligned} & 7.5 \\ & 15 \end{aligned}$ | $\begin{aligned} & \mathrm{pF} \\ & \mathrm{pF} \end{aligned}$ |
| Cout | Output Capacitance (common OUT/IN) |  |  |  |  |  |  |
|  | $\begin{aligned} & \text { CD4051 } \\ & \text { CD4052 } \\ & \text { CD4053 } \end{aligned}$ | $V_{E E}=V_{S S}=0 \mathrm{~V}$ | $\begin{aligned} & 10 \mathrm{~V} \\ & 10 \mathrm{~V} \\ & 10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 30 \\ & 15 \\ & 8 \end{aligned}$ |  | pF pF pF |
| Cios | Feedthrough Capacitance |  |  |  | 0.2 |  | pF |
| CPD | Power Dissipation Capacitance |  |  |  |  |  |  |
|  | $\begin{aligned} & \text { CD4051 } \\ & \text { CD4052 } \\ & \text { CD4053 } \end{aligned}$ |  |  | . | $\begin{aligned} & 110 \\ & 140 \\ & 70 \end{aligned}$ |  | pF pF pF |

Signal Inputs ( $\mathrm{V}_{\text {IS }}$ ) and Outputs ( $\mathrm{V}_{\mathrm{OS}}$ )

|  | Sine Wave Response (Distortion) | $\begin{aligned} & R_{\mathrm{L}}=10 \mathrm{k} \Omega \\ & \mathrm{f}_{\mathrm{IS}}=1 \mathrm{kHz} \\ & \mathrm{~V}_{I S}=5 \mathrm{~V}_{\mathrm{p}-\mathrm{p}} \\ & \mathrm{~V}_{\mathrm{EE}}=\mathrm{V}_{\mathrm{SI}}=0 \mathrm{~V} \end{aligned}$ | 10 V | 0.04 |  | \% |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Frequency Response, Channel "ON" (Sine Wave Input) | $\begin{aligned} & R_{\mathrm{L}}=1 \mathrm{k} \Omega, \mathrm{~V}_{\mathrm{EE}}=\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}, \mathrm{~V}_{I S}=5 \mathrm{~V}_{\mathrm{p}-\mathrm{p}}, \\ & 20 \log _{10} \mathrm{~V}_{\mathrm{OS}} / \mathrm{V}_{I S}=-3 \mathrm{~dB} \end{aligned}$ | 10V | 40 |  | MHz |
|  | Feedthrough, Channel "OFF" | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega, \mathrm{~V}_{\mathrm{EE}}=\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}, \mathrm{~V}_{I S}=5 \mathrm{~V}_{\mathrm{p}-\mathrm{p}}, \\ & 20 \log 10 \mathrm{~V}_{\mathrm{OS}} / V_{I S}=-40 \mathrm{~dB} \end{aligned}$ | 10 V | 10 |  | MHz |
|  | Crosstalk Between Any Two Channels (frequency at 40 dB ) | $\begin{aligned} & R_{L}=1 \mathrm{k} \Omega, V_{E E}=V_{S S}=0 \mathrm{~V}, V_{I S}(A)=5 V_{\mathrm{D}-\mathrm{D}} \\ & 20 \log _{10} \mathrm{~V}_{\mathrm{OS}}(\mathrm{~B}) / \mathrm{V}_{I S}(\mathrm{~A})=-40 \mathrm{~dB}(\text { Note } 3) \end{aligned}$ | 10 V | 3 |  | MH/, |
| tPHL, tpLH | Propagation Delay Signal Input to Signal Output | $\begin{aligned} & V_{E E}=V_{S S}=0 V \\ & C_{L}=50 \mathrm{pF} \end{aligned}$ | $\begin{gathered} 5 \mathrm{~V} \\ 10 \mathrm{~V} \\ 15 \mathrm{~V} \end{gathered}$ | $\begin{aligned} & 25 \\ & 15 \\ & 10 \end{aligned}$ | 55 35 25 | $\begin{aligned} & \text { us } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |

Control Inputs, A, B, C and Inhibit

|  | Control Input to Signal <br> Crosstalk | $V_{E E}=V_{S S}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ at both ends <br> of channel. <br> Input Square Wave Amplitude $=10 \mathrm{~V}$ | 10 V | 65 |  | mV (peak) |  |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| tPHL, | Propagation Delay Time from <br> Address to Signal Output <br> (channels "ON" or "OFF") | $\mathrm{V}_{E E}=\mathrm{VSS}=0 \mathrm{~V}$ <br> $\mathrm{CL}_{\mathrm{L}}=50 \mathrm{pF}$ | 5 V | 10 V | 500 | 1000 | ns |
|  |  | 180 | 360 | ns |  |  |  |
| ns |  |  |  |  |  |  |  |

Note 3: A, B are two arbitrary channels with A turned "ON" and B "OFF".
CD4051BM/CD4051BC, CD4052BM/CD4052BC
CD4053BM/CD4053BC

## Block Diagrams



CD4051BM/CD4051BC .


Block Diagrams (Cont'd.)


Truth Table

| INPUT STATES |  |  |  | "ON" CHANNELS |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| INHIBIT | C | B | A | CD4051B | CD4052B | CD4053B |  |
| 0 | 0 | 0 | 0 | 0 | $0 X, 0 Y$ | $c x, b x, a x$ |  |
| 0 | 0 | 0 | 1 | 1 | $1 \times, 1 Y$ | $c x, b x, a y$ |  |
| 0 | 0 | 1 | 0 | 2 | $2 X, 2 Y$ | $c x, b y, a x$ |  |
| 0 | 0 | 1 | 1 | 3 | $3 X, 3 Y$ | $c x, b y, a y$ |  |
| 0 | 1 | 0 | 0 | 4 |  | $c y, b x, a x$ |  |
| 0 | 1 | 0 | 1 | 5 |  | $c y, b x, a y$ |  |
| 0 | 1 | 1 | 0 | 6 |  | $c y, b y, a x$ |  |
| 0 | 1 | 1 | 1 | 7 |  | $c y, b y, a y$ |  |
| 1 | $*$ | $*$ | $*$ | NONE | NONE | NONE |  |

[^20]CD4052BM/CD4052BC CD4051BM/CD4051BC,
CD4053BM/CD4053BC

Switching Time Waveforms



## Special Considerations

In certain applications the external load-resistor current may include both $\mathrm{V}_{\mathrm{DD}}$ and signal-line components. To avoid drawing $\mathrm{V}_{\mathrm{DD}}$ current when switch current flows into IN/OUT pin, the voltage drop across the bidirec-

## Typical Performance Characteristics

"ON" Resistance vs Signal
Voltage for $T_{A}=\mathbf{2 5}$ C

"ON" Resistance as a
Function of Temperature for
$v_{D D}-V_{E E}=10 \mathrm{~V}$

tional switch must not exceed 0.6 V at $\mathrm{T}_{\mathrm{A}} \leqslant 25^{\circ} \mathrm{C}$, or 0.4 V at $\mathrm{T}_{\mathrm{A}}>25^{\circ} \mathrm{C}$ (calculated from $\mathrm{R}_{\mathrm{ON}}$ values shown). No $V_{D D}$ current will flow through $R_{L}$ if the switch current flows into OUT/IN pin.

## CD4066BM/CD4066BC Quad Bilateral Switch

## General Description

The CD4066BM/CD4066BC is a quad bilateral switch intended for the transmission or multiplexing of analog or digital signals. It is pin-for-pin compatible with CD4016BM/CD4016BC, but has a much lower "ON" resistance, and "ON" resistance is relatively constant over the input-signal range.

## Features

- Wide supply voltage range
- High noise immunity
- Wide range of digital and analog switching
- "ON" resistance for 15 V operation

> 3 V to 15 V
> $0.45 \mathrm{~V}_{\text {DD }}$ (typ.)
> $\pm 7.5 \mathrm{~V}_{\text {PEAK }}$
$80 \Omega$

- Matched "ON" resistance over 15 V signal input
- "ON" resistance flat over peak-to-peak signal range
- High "ON"/"OFF" output voltage ratio
- High degree linearity

65 dB (typ.)
@ $\mathrm{f}_{\text {is }}=10 \mathrm{kHz}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$
$0.1 \%$ distortion (typ.) @ $f_{\text {is }}=1 \mathrm{kHz}, \mathrm{V}_{\text {is }}=5 \mathrm{~V}_{\mathrm{p} \cdot \mathrm{p}}$, $V_{D D}-V_{S S}=10 \mathrm{~V}, R_{L}=10 \mathrm{k} \Omega$

- Extremely low "OFF"
switch leakage
0.1 nA (typ.) @ $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=10 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
- Extremely high control input impedance $10^{12} \Omega$ (typ.)

| - Low crosstalk | -50 dB (typ.) |
| :--- | ---: | ---: |
| between switches$\quad$ @ $\mathrm{f}_{\text {is }}=0.9 \mathrm{MHz}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ |  |
| Frequency response, switch "ON" | 40 MHz (typ.) |

## Applications

- Analog signal switching/multiplexing
- Signal gating
- Squelch control
- Chopper
- Modulator/Demodulator
- Commutating switch
- Digital signal switching/multiplexing
- CMOS logic implementation
- Analog-to-digital/digital-to-analog conversion
- Digital control of frequency, impedance, phase, and analog-signal-gain


## Schematic and Connection Diagrams



TOP VIEW

Absolute Maximum Ratings
(Notes 1 and 2)

| $V_{\text {DD }}$ Supply Voltage | -0.5 V to +18 V |
| :--- | ---: |
| $\mathrm{~V}_{\text {IN }}$ Input Voltage | -0.5 V to $\mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}$ |
| $\mathrm{~T}_{S}$ Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| $\mathrm{P}_{\mathrm{D}}$ Package Dissipation | 500 mW |
| $\mathrm{~T}_{\text {L }}$ Lead Temperature (Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ |

$V_{\text {DD }}$ Supply Voltage $\mathrm{T}_{\mathrm{S}}$ Storage Temperature Range
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
(Note 2)
$V_{D D}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4066BM
CD4066BC

3 V to 15 V $O V$ to $V_{D D}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

DC Electrical Characteristics CD4066BM (Note 2)

| Parameter |  | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Typ | Max | Min | Max |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.25 |  | 0.01 | 0.25 |  | 7.5 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.5 |  | 0.01 | 0.5 |  | 15 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 1.0 |  | 0.01 | 1.0 |  | 30 | $\mu \mathrm{A}$ |


| Signal Inputs and Outputs |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| RON "ON" Resistance | $\begin{aligned} & R_{L}=10 \mathrm{k} \Omega \text { to } \frac{V_{D D}-V_{S S}}{2} \\ & V_{C}=V_{D D}, V_{I S}=V_{S S} \text { to } V_{D D} \\ & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 2000 \\ & 400 \\ & 220 \end{aligned}$ |  | $\begin{aligned} & 270 \\ & 120 \\ & 80 \end{aligned}$ | $\begin{aligned} & 2500 \\ & 500 \\ & 280 \end{aligned}$ |  | $\begin{aligned} & 3500 \\ & 550 \\ & 320 \end{aligned}$ | $\Omega$ $\Omega$ $\Omega$ |
| $\triangle R_{O N} \triangle$ "ON" Resistance Between any 2 of 4 Switches | $\begin{aligned} & R_{L}=10 \mathrm{k} \Omega \text { to } \frac{V_{D D}-V_{S S}}{2} \\ & V_{C}=V_{D D}, V_{I S}=V_{S S} \text { to } V_{D D} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  |  |  | $\begin{aligned} & 10 \\ & 5 \end{aligned}$ |  |  |  | $\Omega$ $\Omega$ |
| IIS Input or Output Leakage Switch "OFF" | $\begin{aligned} & V_{C}=0 \\ & V_{I S}=15 \mathrm{~V} \text { and } 0 \mathrm{~V}, \\ & V_{O S}=0 \mathrm{~V} \text { and } 15 \mathrm{~V} \end{aligned}$ |  | $\pm 50$ |  | $\pm 0.1$ | $\pm 50$ |  | $\pm 500$ | nA |
| Control Inputs |  |  |  |  |  |  |  |  |  |
| VILC Low Level Input Voltage | $\begin{aligned} & V_{I S}=V_{S S} \text { and } V_{D D} \\ & V_{O S}=V_{D D} \text { and } V_{S S} \\ & I_{I S}= \pm 10 \mu \mathrm{~A} \\ & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ |  | $\begin{aligned} & 2.25 \\ & 4.5 \\ & 6.75 \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ | V v |
| VIHC High Level Input Voltage | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \text { (see note } 6 \text { ) } \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 7.0 \\ & 11.0 \end{aligned}$ |  | $\begin{aligned} & 3.5 \\ & 7.0 \\ & 11.0 \end{aligned}$ | $\begin{aligned} & 2.75 \\ & 5.5 \\ & 8.25 \end{aligned}$ |  | $\begin{aligned} & 3.5 \\ & 7.0 \\ & 11.0 \end{aligned}$ |  | V v v |
| IIN Input Current | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=15 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}} \geqslant \mathrm{~V}_{I S} \geqslant \mathrm{~V}_{S S} \\ & \mathrm{~V}_{\mathrm{DD}} \geqslant \mathrm{~V}_{\mathrm{C}} \geqslant \mathrm{~V}_{\mathrm{SS}} \end{aligned}$ |  | $\pm 0.1$ |  | $\pm 10-5$ | $\pm 0.1$ |  | $\pm 1.0$ | $\mu \mathrm{A}$ |

DC Electrical Characteristics CD4066BC (Note 2)

| Parameter | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Typ | Max | Min | Max |  |
| IDD Quiescent Device Current | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 1.0 \\ & 2.0 \\ & 4.0 \end{aligned}$ |  | $\begin{aligned} & 0.01 \\ & 0.01 \\ & 0.01 \end{aligned}$ | $\begin{aligned} & 1.0 \\ & 2.0 \\ & 4.0 \end{aligned}$ |  | $\begin{aligned} & 7.5 \\ & 15 \\ & 30 \end{aligned}$ | $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ |

DC Electrical Characteristics (Cont'd.) CD4066BC (Note 2)


Control Inputs

| VILC Low Level Input Voltage | $\begin{aligned} & V_{I S}=V_{S S} \text { and } V_{D D} \\ & V_{O S}=V_{D D} \text { and } V_{S S} \\ & l_{I S}= \pm 10 \mu \mathrm{~A} \\ & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | 1.5 3.0 4.0 |  | $\begin{aligned} & 2.25 \\ & 4.5 \\ & 6.75 \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ | V v v |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| VIHC High Level Input Voltage | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}(\text { See note } 6) \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 7.0 \\ & 11.0 \end{aligned}$ | $\begin{aligned} & 3.5 \\ & 7.0 \\ & 11.0 \end{aligned}$ | $\begin{aligned} & 2.75 \\ & 5.5 \\ & 8.25 \end{aligned}$ |  | $\begin{aligned} & 3.5 \\ & 7.0 \\ & 11.0 \end{aligned}$ | $\begin{aligned} & v \\ & v \\ & v \end{aligned}$ |
| IIN Input Current | $\begin{aligned} & V_{D D}-V_{S S}=15 \mathrm{~V} \\ & V_{D D} \geqslant V_{I S} \geqslant V_{S S} \\ & V_{D D} \geqslant V_{C} \geqslant V_{S S} \end{aligned}$ | $\pm 0.3$ |  | $\pm 10^{-5}$ | $\pm 0.3$ | $\pm 1.0$ | $\mu \mathrm{A}$ |

AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20$ ns and $\mathrm{V}_{\mathrm{SS}}=\mathrm{OV}$ unless otherwise specified

|  | Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL, tPLH | Propagation Delay Time Signal Input to Signal Output | $\begin{aligned} & V_{C}=V_{D D}, C_{L}=50 \mathrm{pF}, \text { (Figure 1) } \\ & R_{L}=200 \mathrm{k} \\ & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 25 \\ & 15 \\ & 10 \end{aligned}$ | $\begin{aligned} & 55 \\ & 35 \\ & 25 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| tPZH, tPZL | Propagation Delay Time Control Input to Signal Output High Impedance to Logical Level | $R_{\mathrm{L}}=1.0 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, (Figures 2 and 3) $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 125 \\ & 60 \\ & 50 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| tPHZ, tPLZ | Propagation Delay Time Control Input to Signal Output Logical Level to High Impedance | $\mathrm{R}_{\mathrm{L}}=1.0 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, (Figures 2 and 3) $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 125 \\ & 60 \\ & 50 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
|  | Sine Wave Distortion | $\begin{aligned} & V_{C}=V_{D D}=5 \mathrm{~V}, V_{S S}=-5 \mathrm{~V} \\ & R_{L}=10 \mathrm{k} \Omega, V_{I S}=5 V_{p-p}, f=1 \mathrm{kHz}, \\ & \text { (Figure 4) } \end{aligned}$ |  | 0.1 |  | \% |
|  | Frequency Response-Switch "ON" (Frequency at -3 dB) | $\begin{aligned} & V_{C}=V_{D D}=5 \mathrm{~V}, V_{S S}=-5 \mathrm{~V}, \\ & R_{\mathrm{L}}=1 \mathrm{k} \Omega, V_{I S}=5 V_{p-p}, \\ & 20 \text { Log } 10 V_{O S} / V_{O S}(1 \mathrm{kHz})-\mathrm{dB}, \\ & \text { (Figure 4) } \end{aligned}$ |  | 40 |  | MHz |

## AC Electrical Characteristics (Continued)

$T_{A}=25^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$ and $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise noted

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | $\begin{aligned} & \text { Feedthrough - Switch "OFF" } \\ & \text { (Frequency at }-50 \mathrm{~dB} \text { ) } \end{aligned}$ | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{SS}}=-5.0 \mathrm{~V}$, $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega, \mathrm{V}_{\mathrm{IS}}=5.0 \mathrm{~V}_{\mathrm{p} \cdot \mathrm{p}}, 20 \log _{10}$, $\mathrm{V}_{\text {OS }} / V_{\text {IS }}=-50 \mathrm{~dB}$, (Figure 4) |  | 1.25 |  |  |
|  | Crosstalk Between Any Two Switches (Frequency at -50 dB ) | $\begin{aligned} & V_{D D} V_{C(A)}=5.0 \mathrm{~V} ; \mathrm{V}_{S S}=V_{C(B)}=-5.0 \mathrm{~V}, \\ & \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega, \mathrm{~V}_{I S(A)}=5.0 \mathrm{~V}_{p-p,}, 20 \log _{10}, \\ & \left.\mathrm{~V}_{\mathrm{OS}(\mathrm{~B})} \mathrm{V}_{1 \mathrm{IS}(\mathrm{~A})}=-50 \mathrm{~dB}, \text { Figure } 5\right) \end{aligned}$ |  | 0.9 |  | MHz |
|  | Crosstalk; Control Input to Signal Output | $V_{D D}=10 \mathrm{~V}, R_{L}=10 \mathrm{k} \Omega, \mathrm{R}_{\mathrm{IN}}=1.0 \mathrm{k} \Omega$, <br> $V_{C C}=10 \mathrm{~V}$ Square Wave, $C_{L}=50 \mathrm{pF}$ <br> (Figure 6) |  | 150 |  | $m V_{p-p}$ |
|  | Maximum Control Input | $\begin{aligned} & R_{\mathrm{L}}=1.0 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \text { (Figure 7) } \\ & \mathrm{V}_{\mathrm{OS}(\mathrm{f})}=1 / 2 \mathrm{~V} \mathrm{~V}_{\mathrm{V}}(1.0 \mathrm{kHz}) \\ & \mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 6.0 \\ & 8.0 \\ & 8.5 \end{aligned}$ |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $\mathrm{C}_{\text {is }}$ | Signal Input Capactance |  |  | 8.0 |  | pF |
| Cos | Signal Output Capacitance | $V_{\text {DD }}=10 \mathrm{~V}$ |  | 8.0 |  | pF |
| $\mathrm{C}_{\text {ios }}$ | Feedthrough Capacitance | $\mathrm{V}_{\mathrm{C}}=0 \mathrm{~V}$ |  | 0.5 |  | pF |
| $\mathrm{C}_{\text {IN }}$ | Control Input Capacitance |  |  | 5.0 | 7.5 | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $V_{S S}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: These devices should not be connected to circuits with the power "ON".
Note 4: In all cases, there is approximately 5 pF of probe and jig capacitance in the output; however, this capacitance is included in $\mathrm{C}_{\mathrm{L}}$ wherever it is specified.
Note 5: $V_{I S}$ is the voltage at the in/out pin and $V_{O S}$ is the voltage at the out/in pin. $V_{C}$ is the voltage at the control input.
Note 6: Conditions for $V_{I H C}$ :
a) $V_{I S}=V_{D D}, I_{O S}=$ standard $B$ series $I_{O H}$
b) $\mathrm{V}_{\text {IS }}=0 \mathrm{~V}$, IoL $=$ standard B series loL.

## AC Test Circuits and Switching Time Wáveforms



FIGURE 1. tPHL, tPLH Propagation Delay Time Signal Input to Signal Output


FIGURE 2. tPZH. tPHZ Propagation Delay Time Control to Signal Output


FIGURE 3. tpZl, tplZ Propagation Delay Time Control to Signal Output

## AC Test Circuits and Switching Time Waveforms (Cont'd.)


$V_{C}=V_{D D}$ for distortion and frequency response tests $V_{C}=V_{S S}$ for feedthrough test
FIGURE 4. Sine Wave Distortion, Frequency Response and Feedthrough

$\mathrm{V} \mathrm{S}(1) \mathrm{O}$

FIGURE 5. Crosstalk Between Any Two Switches


FIGURE 6. Crosstalk: Control Input to Signal Output

vos


FIGURE 7. Maximum Control Input Frequency

Typical Performance Characteristics

＂ON＂Resistance as a Function of Temperature for $V_{D D}-V_{S S}=10 V$


## Special Considerations

In applications where separate power sources are used to drive $V_{D D}$ and the signal input，the $V_{D D}$ current capability should exceed $V_{D D} / R_{L} / R_{L}=$ effective external load of the 4 CD4066BM／CD4066BC bilateral switches）．This provision avoids any permanent current flow or clamp action on the $V_{D D}$ supply when power is applied or removed from CD4066BM／CD4066BC．

In certain applications，the external load－resistor current may include both $V_{D D}$ and signal－line components．To
＂ON＂Resistance as a Function of Temperature for
$V_{D D}-V_{S S}=15 V$

＂ON＂Resistance as a Function of Temperature for

$$
V_{D D}-V_{S S}=5 V
$$


avoid drawing VDD current when switch current flows into terminals $1,4,8$ or 11 ，the voltage drop across the bidirectional switch must not exceed 0.6 V at $\mathrm{T}_{\mathrm{A}} \leq 25^{\circ} \mathrm{C}$ ， or 0.4 V at $\mathrm{T}_{\mathrm{A}}>25^{\circ} \mathrm{C}$（calculated from RON values shown）．

No $V_{D D}$ current will flow through $R_{L}$ if the switch current flows into terminals $2,3,9$ or 10.

## $V$ <br> National Semiconductor <br> CD4069M/CD4069C Inverter Circuits

## General Description

The CD4069B consists of six inverter circuits and is manufactured using complementary MOS (CMOS) to achieve wide power supply operating range, low power consumption, high noise immunity, and symmetric controlled rise and fall times.
This device is intended for all general purpose inverter applications where the special characteristics of the MM74C901, MM74C903, MM74C907, and CD4049A Hex Inverter/Buffers are not required. In those applications requiring larger noise immunity the MM74C14 or MM74C914 Hex Schmitt Trigger is suggested.

All inputs are protected from damage due to static discharge by diode clamps to $V_{D D}$ and $V_{S S}$.

## Features

| - Wide supply voltage range | 3.0 V to 15 V |
| :--- | :--- |
| - High noise immunity | $0.45 \mathrm{~V}_{\mathrm{DD}}$ typ. |

- Low power TTL fan out of 2 driving 74L compatibility or 1 driving 74LS

■ Equivalent to MM54C04/MM74C04

## Schematic and Connection Diagrams

Dual-In-Line Package


TOP VIEW

## AC Test Circuits and Switching Time Waveforms



Absolute Maximum Ratings
(Notes 1 and 2)

VDD dc Supply Voltage
VIN Input Voltage
TS Storage Temperature Range
$P_{D}$ Package Dissipation
TL Lead Temperature (Soldering, 10 seconds)
-0.5 to $+18 \mathrm{~V}_{\mathrm{DC}}$
-0.5 to $V_{D D}+0.5 V_{D C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$300^{\circ} \mathrm{C}$
(Note 2)

| $V_{D D}$ dc Supply Voltage | 3 to $15 V_{D C}$ |
| :--- | ---: |
| $V_{\text {IN }}$ Input Voltage | 0 to $V_{D D} V_{D C}$ |
| $T_{A}$ Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD4069 M | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

## DC Electrical Characteristics

CD4069M (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V} \quad{ }^{\prime}$. |  | 0.25 |  |  | 0.25 |  | 7.5 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.5 |  |  | 0.5 |  | 15 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 1.0 |  |  | 1.0 |  | 30 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {OL }}$ | Low Level Output Voltage | $\\|_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\mathrm{IIO}^{\mathrm{O}}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level Input Voltage | $\\| \mathrm{O} \mid<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {DD }}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=4.5 \mathrm{~V}$ |  | 1.5 |  |  | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9 \mathrm{~V}$ |  | 3.0 |  |  | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ |  | 4.0 |  |  | 4.0 |  | 4.0 | V |
| $V_{\text {IH }}$ | High Level Input Voltage | $\left.\right\|^{0} \mathrm{O} \mid<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ | 3.5 |  | 3.5 |  |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ | 7.0 |  | 7.0 |  |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 11.0 |  | 11.0 |  |  | 11.0 |  | V |
| ${ }^{\text {IOL }}$ | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V}$ |  |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | $-0.10$ |  | $-10^{-5}$ | $-0.10$ |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.10 |  | $10^{-5}$ | 0.10 |  | 1.0 | $\mu \mathrm{A}$ |

DC Electrical Characteristics CD4069C (Note 2)


AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}, \mathrm{t}_{\mathrm{r}}$ and $\mathrm{t}_{\mathrm{f}} \leqslant 20 \mathrm{~ns}$, unless otherwise specified

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL or tPLH | Propagation Delay Time From Input To Output | $V_{D D}=5 \mathrm{~V}$ |  | 50 | 90 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 30 | 60 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 25 | 50 | ns |
| tTHL or tTLH | Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 80 | 150 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| CIN | Average Input Capacitance | Any Gate |  | 6 | 7.5 | pF |
| CPD | Power Dissipation Capacitance | Any Gate (Note 3) |  | 12 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: CPD determines the no load ac power consumption of any CMOS device. For complete explanation, see 54C/74C Family Characteristics application note-AN-90.

## Typical Performance Characteristics

Power Dissipation vs Frequency


Propagation Delay vs Ambient Temperature


Propagation Delay Time vs Load Capacitance
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National Semiconductor

## CD4070BM/CD4070BC Quad 2-Input EXCLUSIVE-OR Gate

## General Description

Employing complementary MOS (CMOS) transistors to achieve wide power supply operating range, low power consumption, and high noise margin, this gate provides basic functions used in the implementation of digital integrated circuit systems. The N - and P-channel enhancement mode transistors provide a symmetrical circuit with output swing essentially equal to the supply voltage. No DC power other than that caused by leakage current is consumed during static condition. All inputs are protected from damage due to static discharge by diode clamps to $V_{D D}$ and $V_{S S}$.

Features

- Wide supply voltage range
3.0 V to 15 V
- High noise immunity
- Low power TTL compatibility
$0.45 \mathrm{~V}_{\mathrm{DD}}$ typ.
fan out of 2 driving 74L
or 1 driving 74LS
- Pin compatible to CD4030A
- Equivalent to MM54C86/MM74C86 and MC14507B


## Connection Diagram

Dual-In-Line Package


## Typical Performance Characteristics



Truth Table

| INPUTS |  | OUTPUTS |
| :---: | :---: | :---: |
| A | $B$ | $Y$ |
| L | L | L |
| L | $H$ | $H$ |
| $H$ | L | $H$ |
| $H$ | $H$ | L |

Absolute Maximum Ratings
(Notes 1 and 2)
$V_{D D}$ DC Supply Voltage
$V_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
PD Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
-0.5 to $+18 V_{D C}$ -0.5 to $V_{D D}+0.5 V_{D C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW $300^{\circ} \mathrm{C}$
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4070BC CD4070BM

DC Electrical Characteristics CD4070BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 0.25 | . |  | 0.25 |  | 7.5 | $\mu \mathrm{A}$ |
|  |  |  |  | 0.5 |  |  | 0.5 |  | 15 | $\mu \mathrm{A}$ |
|  |  |  |  | 1.0 |  |  | 1.0 |  | 30 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\\| \mathrm{O} \mid<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {DD }}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\left\|{ }^{0}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| VIL | Low Level Input Voltage | $\left\|{ }^{O}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.5 \mathrm{~V}$ |  | 1.5 |  |  | 1.5 |  | 1.5 | v |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9 \mathrm{~V}$ |  | 3.0 |  |  | 3.0 |  | 3.0 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ |  | 4.0 |  |  | 4.0 |  | 4.0 | V |
| $V_{\text {IH }}$ | High Level Input Voltage | $\\| \mathrm{l} \mathrm{V}^{\prime}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 3.5 |  | 3.5 |  |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ | 7.0 |  | 7.0 |  |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ | 11.0 |  | 11.0 |  |  | 11.0 |  | v |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | 10-5 | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

DC Electrical Characteristics CD4070BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 1.0 |  |  | 1.0 |  | 7.5 | $\mu \mathrm{A}$ |
|  |  |  |  | 2.0 |  |  | 2.0 |  | 15 | $\mu \mathrm{A}$ |
|  |  |  |  | 4.0 |  |  | 4.0 |  | 30 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {OL }}$ | Low Level Output Voltage | $\\|_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\mid \mathrm{I}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| $V_{\text {IL }}$ | Low Level Input Voltage | $\left\|\mathrm{V}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ |  | 1.5 |  |  | 1.5 |  | 1.5 | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ |  | 3.0 |  |  | 3.0 |  | 3.0 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ |  | 4.0 |  |  | 4.0 |  | 4.0 | v |
| $V_{\text {IH }}$ | High Level Input Voltage | $\\|_{0} \mid<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.5 \mathrm{~V}$ |  |  | 3.5 |  |  | 3.5 |  |  |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9 \mathrm{~V}$ | 7.0 |  | 7.0 |  |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | 11.0 |  |  |  |  | 11.0 |  | $v$ |
| ${ }^{\text {IOL }}$ | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{0}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | -0.52 |  |  |  |  |  |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | - 1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{~K}, \mathrm{t}_{\mathrm{r}}$ and $\mathrm{t}_{\mathrm{f}} \leqslant 20 \mathrm{~ns}$, unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL or tPLH | Propagation Delay Time From Input To Output | $V_{D D}=5 \mathrm{~V}$ |  | 110 | 185 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 90 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 75 | ns |
| ${ }^{\text {t }}$ HL or t ${ }^{\text {TLLH }}$ | Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| $\mathrm{CIN}_{\text {I }}$ | Average Input Capacitance | Any Input |  | 5 | 7.5 | pF |
| CPD | Power Dissipation Capacitance | Any Input (Note 3) |  | 20 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: CPD determines the no load ac power consumption of any CMOS device. For complete explanation, see 54C/74C Family Characteristics application note-AÑ-90.

## AC Test Circuit and Switching Time Waveforms



Note: Delays measured with input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$.


## CD4071BM/CD4071BC Quad 2-Input OR Buffered B Series Gate CD4081BM/CD4081BC Quad 2-Input AND Buffered B Series Gate

## General Description

These quad gates are monolithic complementary MOS (CMOS) integrated circuits consructed with N - and P channel enhancement mode transistors. They have equal source and sink current capabilities and conform to standard B series output drive. The devices also have buffered outputs which improve transfer characteristics by providing very high gain.
All inputs protected against static discharge with diodes to $V_{D D}$ and $V_{S S}$.

## Features

- Low power TTL compatibility
fan out of 2 driving 74L
or 1 driving 74LS
- 5V-10-15 V parametric ratings
- Symmetrical output characteristics
- Maximum input leakage $1 \mu \mathrm{~A}$ at 15 V over full temperature range


## Schematic and Connection Diagrams



CD4071B
Dual-In-Line and Flat Package


CD4081B
Dual-In-Line and Flat Package


## Absolute Maximum Ratings

(Notes 1 and 2)
Voltage at Any Pin
Package Dissipation
$V_{D D}$ Range
Storage Temperature
Lead Temperature (Soldering, 10 seconds)

DC Electrical Characteristics - CD4071BM/CD4081BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.25 |  | 0.004 | 0.25 |  | 7.5 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.50 |  | 0.005 | 0.50 |  | 15 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 1.0 |  | 0.006 | 1.0 |  | 30 | $\mu \mathrm{A}$ |
| VoL | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $\left.V_{D D}=10 \mathrm{~V}\right\} \mid{ }^{\circ} \mathrm{l}$ < $<1 \mu \mathrm{~A}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| VIL | Low Level Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ |  | 1.5 |  | 2 | 1.5 |  | 1.5 | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ |  | 3.0 |  | 4 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ |  | 4.0 |  | 6 | 4.0 |  | 4.0 | $v$ |
| $\mathrm{V}_{\mathrm{IH}}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=4.5 \mathrm{~V}$ | 3.5 |  | 3.5 | 3 |  | 3.5 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.0 \mathrm{~V}$ | 7.0 |  | 7.0 | 6 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | 11.0 |  | 11.0 | 9 |  | 11.0 |  | V |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| 1 OH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| IN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V}$ |  | -0.10 |  | $-10^{-5}$ | -0.10 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.10 |  | $10^{-5}$ | 0.10 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: All voltages measured with respect to $V_{S S}$ unless otherwise specified.

DC Electrical Characteristics

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| ${ }^{\prime} \mathrm{DD}$ | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 1 |  | 0.004 | 1 |  | 7.5 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 2 |  | 0.005 | 2 |  | 15 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 4 |  | 0.006 | 4 |  | 30 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ ) |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $V$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $\left.V_{D D}=10 \mathrm{~V}\right\}\left\|{ }^{\prime} \mathrm{O}\right\|<1 \mu \mathrm{~A}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ |  | 1.5 |  | 2 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ |  | 3.0 |  | 4 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ |  | 4.0 |  | 6 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{\text {IH }}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.5 \mathrm{~V}$ | 3.5 |  | 3.5 | 3 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.0 \mathrm{~V}$ | 7.0 |  | 7.0 | 6 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | 11.0 |  | 11.0 | 9 |  | 11.0 |  | V |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| $\mathrm{IOH}^{\prime}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | $-3.0$ | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.30 |  | $-10^{-5}$ | -0.30 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.30 |  | $10^{-5}$ | 0.30 |  | 1.0 | $\mu \mathrm{A}$ |

## AC Electrical Characteristics

$\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, Input $\mathrm{t}_{\mathrm{r}} ; \mathrm{t}_{\mathrm{f}}=20$ ns. $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} . \mathrm{R}_{\mathrm{L}}=200 \mathrm{~K} \Omega$ Typical temperature coefficient is $0.3 \% /{ }^{\circ} \mathrm{C}$

|  | PARAMETER | CONDITIONS | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ${ }^{\text {tPHL }}$ | Propagation Delay Time, High-to-Low Level | $V_{D D}=5 \mathrm{~V}$ | 100 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 40 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 30 | 70 | ns |
| tPLH | Propagation Delay Time, Low-to-High Level | $V_{D D}=5 \mathrm{~V}$ | 90 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 40 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 30 | 70 | ns |
| tTHL, TTLH | Transition Time | $V_{D D}=5 \mathrm{~V}$ | 90 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 40 | 80 | ns |
| CIN | Average Input Capacitance | Any Input | 5 | 7.5 | pF |
| CPD | Power Dissipation Capacity | Any Gate | 18 |  | pF |

## AC Electrical Characteristics CD4081BC/CD4081BM

$T_{A}=25^{\circ} \mathrm{C}$, Input $\mathrm{t}_{\mathrm{r}} ; \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns} . \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} . \mathrm{R}_{\mathrm{L}}=200 \mathrm{~K}$ Typical temperature coefficient is $0.3 \% /{ }^{\circ} \mathrm{C}$

|  | PARAMETER | CONDITIONS | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL | Propagation Delay Time, High-to-Low Level | $V_{D D}=5 \mathrm{~V}$ | 100 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 40 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 30 | 70 | ns |
| tPLH | Propagation Delay Time, Low-to-High Level | $V_{D D}=5 \mathrm{~V}$ | 120 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 35 | 70 | ns |
|  | Transition Time | $V_{D D}=5 \mathrm{~V}$ | 90 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 40 | 80 | ns |
| CIN | Average Input Capacitance | Any Input | 5 | 7.5 | pF |
| CPD | Power Dissipation Capacity | Any Gate | 18 |  | pF |

## Typical Performance Characteristics



FIGURE 1. Typical Transfer Characteristics


FIGURE 4. Typical Transfer Characteristics


FIGURE 2. Typical Transfer Characteristics


FIGURE 5


FIGURE 3. Typical Transfer Characteristics


FIGURE 6

Typical Performance Characteristics (Cont'd.)


FIGURE 7


FIGURE 10


FIGURE 8


FIGURE 11


FIGURE 9


FIGURE 12


FIGURE 13


FIGURE 14

## CD4072BM/CD4072BC Dual 4-Input OR Gate, CD4082BM/CD4082BC Dual 4-Input AND Gate

## General Description

These dual gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N -and P-channel enhancement mode transistors. They have equal source and sink current capabilities and conform to standard B series output drive. The devices also have buffered outputs which improve transfer characteristics by providing very high gain. All inputs are protected against static discharge with diodes to $V_{D D}$ and $V_{S S}$.

Features

- Wide supply voltage range
3.0V to 15 V
$0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
- High noise immunity
- Low power TTL compatibility
fanout of 2 driving 74L or 1 driving 74LS
- 5V-10V-15V parametric ratings
- Symmetrical output characteristics
- Maximum input leakage $1 \mu \mathrm{~A}$ at 15 V over full temperature range


## Connection Diagram

CD4072BM/CD4072BC


CD4082BM/CD4082BC


Absolute Maximum Ratings (Notes 1 and 2)
$V_{D D}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{S}}$ Storage Temperature Range
$P_{D}$ Package Dissipation
$T_{L}$ Lead Temperature (soldering, 10 seconds)
-0.5 V to +18 V
-0.5 to $V_{D D} 0.5 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW $300^{\circ} \mathrm{C}$

## Recommended Operating Conditions (Note 2)

$V_{D D}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
$T_{A}$ Operating Temperature Range
CD4072BM, CD4082BM
CD4072BC, CD4082BC
3.0 to 15 V
$O V$ to $V_{D D} V$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

DC Electrical Characteristics (Note 2) - CD4072BM, CD4082BM

| Parameter |  | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| $I_{\text {DD }}$ | Quiescent |  | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  | 0.25 |  | 0.004 | 0.25 |  | 7.5 | $\mu \mathrm{A}$ |
|  | Device Current | $V_{D D}=10 \mathrm{~V}$ |  | 0.5 |  | 0.005 | 0.5 |  | 15 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 1.0 |  | 0.006 | 1.0 |  | 30 | $\mu \mathrm{A}$ |
| VOL | Low Level | $V_{D D}=5.0 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | Output Voltage | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level | $V_{D D}=5.0 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  | Output Voltage | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  | Input Voltage | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  | Input Voltage | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| IOL | Low Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  | Output Current | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.2 |  | 0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.0 |  | 2.4 |  | mA |
| $\mathrm{IOH}^{\text {O }}$ | High Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  | Output Current | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.2 |  | -0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.0 |  | -2.4 |  | mA |
| $\mathrm{I}_{\mathrm{N}}$ | Input Current | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.10 |  | $-10^{-5}$ | -0.10 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.10 |  | $10^{-5}$ | 0.10 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

DC Electrical Characteristics (Note 2) - CD4072BC, CD4082BC

| Parameter |  | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| $\mathrm{I}_{\mathrm{DD}}$ | Quiescent |  | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  | 1.0 |  | 0.004 | 1.0 |  | 7.5 | $\mu \mathrm{A}$ |
|  | Device Current | $V_{D D}=10 \mathrm{~V}$ |  | 2.0 |  | 0.005 | 2.0 |  | 15 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 4.0 |  | 0.006 | 4.0 |  | 30 | $\mu \mathrm{A}$ |
| VoL | Low Level | $V_{\text {DD }}=5.0 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $\checkmark$ |
|  | Output Voltage | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level | $V_{D D}=5.0 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | $v$ |
|  | Output Voltage | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | $v$ |
| $\mathrm{V}_{\mathrm{IL}}$ | Low Level | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  | Input Voltage | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | $v$ |
| $\mathrm{V}_{\mathrm{IH}}$ | High Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  | Input Voltage | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | v |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| IOL | Low Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  | Output Current | $\mathrm{V}_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.2 |  | 0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.0 |  | 2.4 |  | mA |
| 1 IOH | High Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  | Output Current | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.2 |  | -0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8.0 |  | -2.4 |  | mA |
| In | Input Current | $V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V}$ |  | $-0.3$ |  | $-10^{-5}$ | $-0.3$ |  | -1.0 1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}^{\prime} \mathrm{N}=15 \mathrm{~V}$ |  |  |  |  |  |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise noted.

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {PHL }}$ | Propagation Delay, High to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 125 \\ & 60 \\ & 45 \end{aligned}$ | $\begin{aligned} & 250 \\ & 100 \\ & 70 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| ${ }_{\text {tplh }}$ | Propagation Delay, Low to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 125 \\ & 60 \\ & 45 \end{aligned}$ | $\begin{aligned} & 250 \\ & 100 \\ & 70 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| ${ }^{\text {THL }}$, $\mathrm{t}_{\text {TLH }}$ | Transition Time | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 50 \\ & 40 \end{aligned}$ | $\begin{gathered} 200 \\ 100 \\ 80 \end{gathered}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ | Average Input Capacitance (Note 3) | Any Input |  | 5.0 | 7.5 | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacity (Note 4) | Any Gate |  | 20 |  | pF |

Note 3: Capacitance is guaranteed by periodic testing.
Note 4: $\mathrm{C}_{P D}$ determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics, Application Note AN-90.

## CD4073BM/CD4073BC Double Buffered Triple 3-Input AND Gate <br> CD4075BM/CD4075BC Double Buffered Triple 3-Input OR Gate

## General Description

These triple gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N - and P-channel enhancement mode transistors. They have equal source and sink current capabilities and conform to standard $B$ series output drive. The devices also have buffered outputs which improve transfer characteristics by providing very high gain. All inputs are protected against static discharge with diodes to $V_{D D}$ and $V_{S S}$.

## Features

- Wide supply voltage range
3.0 V to 15 V
- High noise immunity
- Low power TTL compatibility
$0.45 \mathrm{~V}_{\mathrm{DD}}$ typ.
- $5 \mathrm{~V} \cdot-10 \mathrm{~V}-15 \mathrm{~V}$ parametric ratings
- Symmetrical output characteristics
- Maximum input leakage $1 \mu \mathrm{~A}$ at 15 V over full temperature range


## Connection Diagrams



CD4073 Triple 3-Input AND Gate TOP VIEW


CD4075B Triple 3-Input OR Gate
TOP VIEW

Absolute Maximum Ratings (Notes 1 and 2 )
$V_{D D}$ DC Supply Voltage
$-0.5 V_{D C}$ to $+18 V_{D C}$
$V_{\text {IN }}$ Input Voltage $\quad-0.5 V_{D C}$ to $V_{D D}+0.5 V_{D C}$
$\mathrm{T}_{\mathrm{S}} \quad$ Storage Temperature Range $\quad-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
$P_{D}$ Package Dissipation 500 mW
$\mathrm{T}_{\mathrm{L}} \quad$ Lead Temperature (soldering, 10 seconds) $300^{\circ} \mathrm{C}$

Operating Conditions (Note 2)

| $V_{D D}$ DC Supply Voltage | $+5 V_{D C}$ to $+15 V_{D C}$ |
| :--- | ---: |
| $V_{\text {IN }}$ Input Voltage | $0 V_{D C}$ to $V_{D D} V_{D C}$ |
| $T_{A}$ Operating Temperature Range |  |
| $C D 4073 B M / C D 4075 B M$ | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD4073BC/CD4075BC | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

$V_{D D} D C$ Supply Voltage $\quad+5 V_{D C}$ to $+15 V_{D C}$
$V_{I N}$ Input Voltage $\quad 0 V_{D C}$ to $V_{D D} V_{D C}$
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range
CD4073BC/CD4075BC
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## DC Electrical Characteristics CD4073вм/CD4075Bм (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.25 |  | 0.004 | 0.25 |  | 7.5 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.5 |  | 0.005 | 0.5 |  | 15 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 1.0 |  | 0.006 | 1.0 |  | 30 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ ) |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $\left.\mathrm{V}_{\text {DD }}=10 \mathrm{~V}\right\} 1 \mathrm{lol}<1 \mu \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ ) |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output.Voltage | $V_{D D}=5 \mathrm{~V}$ ) | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{\text {DD }}=10 \mathrm{~V} \\| \mid \mathrm{I}_{\mathrm{O}}<1 \mu \mathrm{~A}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ ) | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ |  | 1.5 |  | 2 | 1.5 |  | 1.5 | V |
|  |  | $\left.V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}\right\}\left\|\mathrm{I}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ |  | 3.0 |  | 4 | 3.0 |  | 3.0 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ |  | 4.0 |  | 6 | 4.0 |  | 4.0 | V |
| $V_{\text {IH }}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=4.5 \mathrm{~V}$ | 3.5 |  | 3.5 | 3 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.0 \mathrm{~V},\left\|I_{O}\right\|<1 \mu \mathrm{~A}$ | 7.0 |  | 7.0 | 6 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | 11.0 |  | 11.0 | 9 |  | 11.0 |  | V |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.2 |  | 0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8 |  | 2.4 |  | mA |
| $\mathrm{I}_{\mathrm{OH}}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.2 |  | -0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8 |  | -2.4 |  | mA |
| 1 IN | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.10 |  | $-10^{-5}$ | -0.10 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.10 |  | $10^{-5}$ | 0.10 |  | 1.0 | $\mu \mathrm{A}$ |

Notes on following page.

## Schematic Diagram



DC Electrical Characteristics CD4073BC/CD4075BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 1 |  | 0.004 | 1 |  | 7.5 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 2 |  | 0.005 | 2 |  | 15 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 4 |  | 0.006 | 4 |  | 30 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {OL }}$ | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $\left.V_{\text {DD }}=10 \mathrm{~V}\right\} \mid \mathrm{I}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 | . | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ ) |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $\left.V_{\text {DD }}=10 \mathrm{~V}\right\}\left\|\mathrm{V}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ ) | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| $V_{\text {IL }}$ | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ |  | 1.5 |  | 2 | 1.5 |  | 1.5 | V |
|  |  | $\left.\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}\right\}\left\|\mathrm{I}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ |  | 3.0 |  | 4 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ |  | 4.0 |  | 6 | 4.0 |  | 4.0 | v |
| $\mathrm{V}_{\mathrm{IH}}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=4.5 \mathrm{~V}$, | 3.5 |  | 3.5 | 3 |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.0 \mathrm{~V}$, $\left\|\mathrm{I}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ | 7.0 |  | 7.0 | 6 |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ ) | 11.0 |  | 11.0 | 9 |  | 11.0 |  | v |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.2 |  | 0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8 |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.2 |  | -0.90 |  | mA |
|  |  | $\mathrm{V}_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8 |  | -2.4 |  | mA |
| In | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.30 |  | $-10^{-5}$ | -0.30 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.30 |  | $10^{-5}$ | 0.30 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

## Schematic Diagram



## AC Electrical Characteristics CD4073BM/CD4073BC/CD4075BM/CD4075BC

$T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}$ unless otherwise specified.

| PARAMETER |  | CONDITIONS | $\begin{array}{r} \text { CD4073BC } \\ \text { CD4073BM } \\ \hline \end{array}$ |  |  | $\begin{aligned} & \text { CD4075BC } \\ & \text { CD4075BM } \end{aligned}$ |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP | MAX | MIN | TYP | MAX |  |
| $\mathrm{tPHL}^{\text {P }}$ | Propagation Delay, High to Low Level |  | $\mathrm{V}_{\text {DD }}=5 \mathrm{~V}$ |  | 130 | 250 |  | 140 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 60 | 100 |  | 70 | 100 | ns |
|  |  | $V_{\text {Dn }}=15 \mathrm{~V}$ |  | 40 | 70 |  | 50 | 70 | ns |
| ${ }_{\text {tPLH }}$ | Propagation Delay, Low to High Level | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 140 | 250 |  | 130 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 70 | 100 |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 50 | 70 |  | 40 | 70 | ns |
| ${ }^{\text {t }}$ THL | Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 90 | 200 |  | 90 | 200 | ns |
| ${ }_{\text {t }}^{\text {TLH }}$ |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 |  | 50 | 100 | ns |
|  |  | $\mathrm{V}_{\text {DD }}=15 \mathrm{~V}$ |  | 40 | 80 | , | 40 | 80 | ns |
| $\mathrm{C}_{\text {IN }}$ | Average Input Capacitance (See Note 3) | Any Input |  | 5 | 7.5 |  | 5 | 7.5 | pF |
| $\mathrm{CPD}^{\text {P }}$ | Power Dissipation Capacity (See Note 4) | Any Gate |  | 17 |  |  | 17 |  | pF |

Note 3: Capacitance is guaranteed by periodic testing.
Note 4: CPD determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family characteristics Application Note AN-90.

## CD4076BM/CD4076BC TRI-STATE® Quad D Flip-Flop

## General Description

The CD4076BM/CD4076BC TRI-STATE quad D flip-flop is a monlithic complementary MOS (CMOS) integrated circuit constructed with N - and P-channel enhancement mode transistors. The four D type flip-flops operate synchronously from a common clock. The TRI-STATE output allows the device to be used in bus organized systems. The outputs are placed in the TRI-STATE mode when either of the two output disable pins are in the logic " 1 " level. The input disables allow the flip flops to remain in their present state without disrupting the clock. If either of the two input disables is taken to a logic " 1 " level, the Q outputs are fed back to the inputs and in this manner the flip-flops do not change state.

Clearing is enabled by taking the clear input to a logic "1" level. Clocking occurs on the positive-going transition.
All inputs are protected against damage due to static discharge by diode clamps to $V_{D D}$ and $V_{S S}$.

Features

- Wide supply voltage range
3.0 V to 15 V
- High noise immunity
- Low power TTL compatibility
- High impedance TRI-STATE outputs
- Inputs can be disabled without gating the clock

■ Equivalent to MM54C173/MM74C173

Logic and Connection Diagrams


## Truth Table

| $\mathbf{t}_{\mathbf{n}}$ |  | $\mathbf{t}_{\mathbf{n}+\mathbf{1}}$ |
| :--- | :---: | :---: |
| DATA INPUT DISABLE | DATA |  |
| INPUT |  |  |
| Logic " 1 " on One or Both Inputs | $\times$ | $\mathrm{a}_{\mathbf{n}}$ |
| Logic " 0 " on Both Inputs | 1 | 1 |
| Logic " 0 ' on Both Inputs | 0 | 0 |


| Absolute Maximum Ratin | Ratings (Notes 1 and 2) | Operating Conditions (Note 2) |  |
| :---: | :---: | :---: | :---: |
| $V_{\text {DD }}$ dc Supply Voitage | -0.5 to +18 V $V_{\text {DC }}$ | $V_{\text {DD }}$ dc Supply Voltage | 3 to $15 \mathrm{~V}_{\mathrm{DC}}$ |
| $V_{\text {IN }}$ Input Voltage $\quad-0.5$ | -0.5 to $\mathrm{V}^{\text {D }}$ + $+0.5 \mathrm{~V}_{\text {DC }}$ | $V_{\text {IN }}$ Input Voltage | 0 to $V_{D D} V_{D C}$ |
| TS Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ | $\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range |  |
| $\mathrm{P}_{\mathrm{D}}$ Package Dissipation | 500 mW | CD4076BM | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ Lead Temperature (Soldering, 10 seconds) | nds) $300^{\circ} \mathrm{C}$ | CD4076BC | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

DC Electrical Characteristics CD4076BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| ${ }^{\prime}$ DD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 5 |  |  | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  |  | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  |  | 20 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 |  |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 |  |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 |  |  | 14.95 |  | V |
| VIL | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1 \mathrm{~V} \text { or } 9 \mathrm{~V}$ |  | 3.0 |  |  | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | V |
| $V_{\text {IH }}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{O}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 |  |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | V |
| ${ }^{\text {I OL }}$ | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| ${ }^{\mathrm{I}} \mathrm{OH}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | $-0.64$ |  | $-0.51$ | -0.88 |  | -0.36 |  | $m A$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | $\cdots \wedge$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | $\cdots A$ |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |
| ${ }^{\prime} \mathrm{OZ}$ | Output Current in High | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  | Impedance State | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

## DC Electrical Characteristics CD4076BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 20 |  |  | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  |  | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  |  | 80 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 |  |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 |  |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 |  |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  |  | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | v |
| $\mathrm{V}_{\mathrm{IH}}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 |  |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | v |
| IOL | Low Level Output Current | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8.8 |  | -2.4 |  | mA |

DC Electrical Characteristics (Cont'd.) CD4076BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IIN | Input Current |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | $-0.3$ |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |
| IOZ | Output Current in High | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  | Impedance State | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{~K}$, Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL or tPLH | Propagation Delay Time From Clock to Output | $V_{D D}=5 \mathrm{~V}$ |  | 220 | 400 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 80 | 200 | ns |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 65 | 160 | ns |
| tPHL | Propagation Delay Time From Clear to Output | $V_{D D}=5 \mathrm{~V}$ |  | 240 | 490 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 90 | 180 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 70 | 145 | ns |
| ${ }^{\text {t }} \mathrm{U}$ | Minimum $\begin{aligned} & \text { Mnput Data Set-Up Time }\end{aligned}$ | $V_{D D}=5 \mathrm{~V}$ |  | 40 | 80 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 15 | 30 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 12 | 25 | ns |
| t H | Minimum Input Data Hold Time | $V_{D D}=5 \mathrm{~V}$ |  | -40 | 0 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | -12 | 0 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | -10 | 0 | ns |
| ${ }^{\text {t }} \mathrm{SU}$ | Input Disable Set-Up Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V D D=10 \mathrm{~V}$ |  | 35 | 70 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 28 | 55 | ns |
| ${ }^{t} \mathrm{H}$ | Minimum Input Disable Hold Time | $V_{D D}=5 \mathrm{~V}$ |  | -75 | 0 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | -30 | 0 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | -25 | 0 | ns |
| ${ }^{\text {tP }}$ HZ ${ }^{\text {t }}$ PLZ | Propagation Delay Time From Output | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=1.0 \mathrm{k}$ |  | 170 | 340 | ns |
|  | Disable to High Impedance State | $V_{D D}=10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}} 1.0 \mathrm{k}$ |  | 70 | 140 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{R}_{\mathrm{L}} 1.0 \mathrm{k}$ |  | 56 | 115 | ns |
| tPZH, tPZL | Propagation Delay From Output | $V_{D D}=5 \mathrm{~V}, R_{L}=1.0 \mathrm{k}$ |  | 170 | 340 | ns |
|  | Disable to Logical "1" Level or | $V_{D D}=10 \mathrm{~V}, R_{L}=1.0 \mathrm{k}$ |  | 70 | 140 | ns |
|  | Logical "0" Level (From High Impedance State) | $V_{D D}=15 \mathrm{~V}, R_{L}=1.0 \mathrm{k}$ |  | 56 | 115 | ns |
| tTHL or tTLH | Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| ${ }^{\mathrm{f}} \mathrm{CL}$ | Maximum Clock Frequency | $V_{D D}=5 \mathrm{~V}$ | 3.0 | 4.0 |  | MHz |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 7.0 | 12.0 |  | MHz |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 8.75 | 15.0 |  | MHz |
| ${ }^{\text {t WH }}$ | Minimum Clear Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 150 |  | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 70 |  | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 56 |  | ns |
| ${ }^{\text {t RCL }}$, ${ }^{\text {t }}{ }^{\text {FCL }}$ | Maximum Clock Rise and Fall Time | $V_{D D}=5 \mathrm{~V}$ | 10 |  |  | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 5 |  |  | $\mu \mathrm{s}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ | 2 |  |  | $\mu \mathrm{s}$ |
| CIN | Average Input Capacitance | Data Inputs ( $\mathrm{A}, \mathrm{B}, \mathrm{C}, \mathrm{D}$ ) |  | 3 | 7.5 | pF |
|  |  | Other Inputs |  | 6 | 15 | pF |
| CPD | Power Dissipation Capacity | All Four Flip-Flops, (Note 3) |  | 100 |  | pF |
| COUT | TRI-STATE® Output Capacitance | Any Output |  |  | 15 | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: CPD determines the no load ac power consumption of any CMOS device. For complete explanation, see 54C/74C Family Characteristics application note, AN-90.


## CD4089BM/CD4089BC Binary Rate Multiplier CD4527BM/CD4527BC BCD Rate Multiplier

## General Description

The CD4089B is a 4-bit binary rate multiplier that provides an output pulse rate which is the input clock pulse rate multiplied by $1 / 16$ times the binary input number. For example, if 5 is the binary input number, there will be 5 output pulses for every 16 clock pulses.
The CD4527B is a 4 -bit BCD rate multiplier that provides an output pulse rate which is the input clock pulse rate multiplied by $1 / 10$ times the BCD input number. For example, if 5 is the BCD input number, there will be 5 output pulses for every 10 clock pulses.

These devices may be used to perform arithmetic operations including multiplication and division, A/D and D/A conversion and frequency division.

## Features

- Wide supply voltage range 3.0 V to 15 V
- High noise immunity
- Low power TTL $0.45 \mathrm{~V}_{\mathrm{DD}}$ typ. compatibility fan out of 2 driving 74L or 1 driving 74LS
- Internally synchronous 4-bit counter
- Output clocked on the negative-going edge of clock
- STROBE for inhibiting and enabling outputs
- INHIBIT IN and CASCADE inputs for cascade operation
- Complementary output
- CLEAR and SET inputs
- " 9 " or " 15 " output and INHIBIT OUT output


## Connection Diagrams



TOP VIEW

CD4527B


TOP VIEW

## Absolute Maximum Ratings

(Notes 1 and 2)
$V_{D D}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
$P_{D}$ Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
$300^{\circ} \mathrm{C}$
DC Electrical Characteristics CD4089вм/CD4527BM (note 2)

| PARAMETER |  | CONDITIONS | $-55^{\prime \prime} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 5 |  |  | 5 |  | 150. | $\mu \mathrm{A}$ |
|  |  | $V D D=10 \mathrm{~V}$ |  | 10 |  |  | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  |  | 20 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\\| \mathrm{O} \mid \leq 1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| VOH | High Level Output Voltage | $\\|^{\prime} \mathrm{O} \leq 1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 | - | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1 \mathrm{~V} \text { or } 9 \mathrm{~V}$ |  | 3.0 |  |  | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | $v$ |
| $V_{\text {IH }}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 |  |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | $\checkmark$ |
| ${ }^{\text {IOL }}$ | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | $-1.0$ | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

## DC Electrical Characteristics CD4089BC/CD4527BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| ${ }^{\prime} \mathrm{DD}$ | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 20 |  |  | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  |  | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  |  | 80 | . | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\\| \mathrm{O}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| VOH | High Level Output Voltage | $\|1 \mathrm{O}\| \leq 1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1 \mathrm{~V} \text { or } 9 \mathrm{~V}$ |  | 3.0 |  |  | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | V |
| $V_{\text {IH }}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 |  |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | V |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{O}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ | 3.6 |  | 30 | 8.8 |  | 24 |  | mA |

DC Electrical Characteristics (Cont'd.) CD4089BC/CD4527BC (Note 2)

|  | PARAMETER | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| - ${ }^{\mathrm{IOH}}$ | High Level Output Current | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | $-0.3$ |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

## AC Electrical Characteristics



Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $V_{S S}=O V$ unless otherwise specified.
Note 3: CPD determines the no load ac power consumption of any CMOS device. For complete explanation, see 54C/74C Family Characteristics application note, AN-90.

| INPUTS |  |  |  |  |  |  |  |  |  | NUMBER OF PULSES OR OUTPUT LOGIC LEVEL ( H OR L) |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| D | C | B | A | No. of Clock Pulses | $\mathrm{Inh}_{1 \mathrm{n}}$ | Strobe | Cascade | Clear | Set | $\text { Pin } 6$ Out | $\frac{\text { Pin } 5}{\text { Out }}$ | Pin 7 <br> Inh Out | $\begin{aligned} & \text { Pin 1 } \\ & \text { "15" } \end{aligned}$ |
| 0 | 0 | 0 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | L | H | 1 | 1 |
| 0 | 0 | 0 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 |
| 0 | 0 | 1 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 2 | 2 | 1 | 1 |
| 0 | 0 | 1 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 3 | 3 | 1 | 1 |
| 0 | 1 | 0 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 4 | 4 | 1 | 1 |
| 0 | 1 | 0 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 5 | 5 | 1 | 1 |
| 0 | 1 | 1 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 6 | 6 | 1 | 1 |
| 0 | 1 | 1 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 7 | 7 | 1 | 1 |
| 1 | 0 | 0 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 8 | 8 | 1 | 1 |
| 1 | 0 | 0 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 9 | 9 | 1 | 1 |
| 1 | 0 | 1 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 10 | 10 | 1 | 1 |
| 1 | 0 | 1 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 11 | 11 | 1 | 1 |
| 1 | 1 | 0 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 12 | 12 | 1 | 1 |
| 1 | 1 | 0 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 13 | 13 | 1 | 1 |
| 1 | 1 | 1 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 14 | 14 | 1 | 1 |
| 1 | 1 | 1 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 15 | 15 | 1 | 1 |
| X | X | X | X | 16 | 1 | 0 | 0 | 0 | 0 | Depend | on inter | state of | ounter |
| x | x | x | x | 16 | 0 | 1 | 0 | 0 | 0 | L | H | 1 | 1 |
| X | x | x | x | 16 | 0 | 0 | 1 | 0 | 0 | H | * | 1 | 1 |
| 1 | X | X | X | 16 | 0 | 0 | 0 | 1 | 0 | 16 | 16 | H | L |
| 0 | x | $\times$ | x | 16 | 0 | 0 | 0 | 1 | 0 | L | H | H | L |
| x | x | $\times$ | x | 16 | 0 | 0 | 0 | - | 1 | L | H | L | H |

* Output same as the first 16 lines of this truth table (depending on values of A, B, C, D)

CD4527B
BCD Rate Multiplier

| INPUTS |  |  |  |  |  |  |  |  |  | NUMBER OF PULSES OR OUTPUT LOGIC LEVEL (H OR L) |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| D | C | B | A | No. of Clock Pulses | Inh ${ }^{\text {n }}$ | Strobe | Cascade | Clear | Set | Pin 6 Out | $\begin{aligned} & \text { Pin } 5 \\ & \overline{O u t} \end{aligned}$ | $\begin{aligned} & \text { Pin } 7 \\ & \text { Inh Out } \end{aligned}$ | Pin 1 " 9 " |
| 0 | 0 | 0 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | L | H | 1 | 1 |
| 0 | 0 | 0 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 |
| 0 | 0 | 1 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | 2 | 2 | 1 | 1 |
| 0 | 0 | 1 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 3 | 3 | 1 | 1 |
| 0 | 1 | 0 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | 4 | 4 | 1 | 1 |
| 0 | 1 | 0 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 5 | 5 | 1 | 1 |
| 0 | 1 | 1 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | 6 | 6 | 1 | 1 |
| 0 | 1 | 1 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 7 | 7 | 1 | 1 |
| 1 | 0 | 0 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | 8 | 8 | 1 | 1 |
| 1 | 0 | 0 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 9 | 9 | 1 | 1 |
| 1 | 0 | 1 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | 8 | 8 | 1 | 1 |
| 1 | 0 | 1 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 9 | 9 | 1 | 1 |
| 1 | 1 | 0 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | 8 | 8 | 1 | 1 |
| 1 | 1 | 0 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 9 | 9 | 1 | 1 |
| 1 | 1 | 1 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | 8 | 8 | 1 | 1 |
| 1 | 1 | 1 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 9 | 9 | 1 | 1 |
| X | X | X | X | 10 | 1 | 0 | 0 | 0 | 0 | Depends on internal state of counter |  |  |  |
| X | $x$ | X | $x$ | 10 | 0 | 1 | 0 | 0 | 0 | L | H | 1 | 1 |
| X | $x$ | X | $x$ | 10 | 0 | 0 | 1 | 0 | 0 | H | * | 1 | 1 |
| 1 | X | X | X | 10 | 0 | 0 | 0 | 1 | 0 | 10 | 10 | H | L |
| 0 | X | X | X | 10 | 0 | 0 | 0 | 1 | 0 | L | H | H | L |
| X | X | $\times$ | X | 10 | 0 | 0 | 0 | 0 | 1 | L | H | L. | H |

* Output same as the first 16 lines of this truth table (depending on values of $A, B, C, D$ )


## Logic Waveforms



CD4527B
BCD Rate Multiplier



## Logic Diagrams

CD4089B
Binary Rate Multiplier


CD4527B
BCD Rate Multiplier



Two CD4089B's cascaded in the "add" mode with a preset number of $89\left(\frac{5}{16}+\frac{9}{256}=\frac{89}{256}\right)$


Two CD4089B's cascaded in the "multiply" mode with a preset number of $98\left(\frac{7}{16} \times \frac{14}{16}=\frac{98}{256}\right)$


Two CD4527B's cascaded in the "add" mode with a preset number of $27\left(\frac{2}{10}+\frac{7}{100}=\frac{27}{100}\right)$


Two CD4527B's cascaded in the "multiply" mode with a preset number of $27\left(\frac{3}{10} \times \frac{9}{10}=\frac{27}{100}\right)$

## N National Semiconductor <br> CD4093BM/CD4093BC Quad 2-Input NAND Schmitt Trigger

## General Description

The CD4093B consists of four Schmitt-trigger circuits. Each circuit functions as a 2-input NAND gate with Schmitt-trigger action on both inputs. The gate switches at different points for positive and negative-going signals. The difference between the positive ( $V^{\top}{ }^{+}$) and the negative voltage $\left(\mathrm{V}_{T^{-}}\right)$is defined as hysteresis voltage $\left(\mathrm{V}_{\mathrm{H}}\right)$.

All outputs have equal source and sink currents and conform to standard B-series output drive (see Static Electrical Characteristics).

## Features

- Wide supply voltage range
3.0 V to 15 V

图 Schmitt-trigger on each input with no external components

- Noise immunity greater than 50\%
( Equal source and sink currents
- No limit on input rise and fall time
- Standard B-series output drive
- Hysteresis voltage (any input) $T_{A}=25^{\circ} \mathrm{C}$

| Typical | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{H}}=1.5 \mathrm{~V}$ |
| :--- | :--- | :--- |
|  | $\mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{H}}=2.2 \mathrm{~V}$ |
|  | $\mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{H}}=2.7 \mathrm{~V}$ |
| Guaranteed |  | $\mathrm{V}_{\mathrm{H}}=0.1 \mathrm{~V}_{\mathrm{DD}}$ |

## Applications

- Wave and pulse shapers
n High-noise-environment systems
- Monostable multivibrators
- Astable multivibrators
- NAND logic


## Connection Diagram

Dual-In-Line Package


## Absolute Maximum Ratings

(Notes 1 and 2)
DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}$ )
-0.5 to $+18 V_{D C}$
Input Voltage ( $\mathrm{V}_{\text {IN }}$ )
Storage Temperature Range (TS)
Package Dissipation ( $\mathrm{P}_{\mathrm{D}}$ )
Lead Temperature (Soldering, 10 seconds) ( $T_{L}$

$$
-0.5 \text { to } V_{D D}+0.5 V_{D C}
$$

$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$300^{\circ} \mathrm{C}$

VDD dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4093BM
CD4093BC

DC Electrical Characteristics CD4093вм (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.25 |  |  | 0.25 | , | 7.5 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.5 |  |  | 0.5 |  | 15.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 1.0 |  |  | 1.0 |  | 30.0 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage |  |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {SS }}, \\|_{\mathrm{O}} \mathrm{I}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| $\mathrm{V}_{\text {T- }}$ | Negative-Going Threshold Voltage (Any Input) | $\mid 10 \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.5 \mathrm{~V}$ | 1.3 | 2.25 | 1.5 | 1.8 | 2.25 | 1.5 | 2.3 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9 \mathrm{~V}$ | 2.85 | 4.5 | 3.0 | 4.1 | 4.5 | 3.0 | 4.65 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | 4.35 | 6.75 | 4.5 | 6.3 | 6.75 | 4.5 | 6.9 | v |
| $\mathrm{V}_{\mathrm{T}+}$ | Positive-Going Threshold Voltage (Any Input) | $\|\mathrm{IO}\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | , $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 2.75 | 3.65 | 2.75 | 3.3 | 3.5 | 2.65 | 3.5 | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ | 5.5 | 7.15 | 5.5 | 6.2 | 7.0 | 5.35 | 7.0 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 8.25 | 10.65 | 8.25 | 9.0 | 10.5 | 8.1 | 10.5 | $v$ |
| $\mathrm{V}_{\mathrm{H}}$ | Hysteresis $\left(\mathrm{V}_{\mathrm{T}+}-\mathrm{V}_{\mathrm{T}-}\right.$ ) <br> (Any Inpuit) | $V_{D D}=5 \mathrm{~V}$ | 0.5 | 2.35 | 0.5 | 1.5 | 2.0 | 0.35 | 2.0 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 1.0 | 4.30 | 1.0 | 2.2 | 4.0 | 0.70 | 4.0 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 1.5 | 6.30 | 1.5 | 2.7 | 6.0 | 1.20 | 6.0 | v |
| ${ }^{\prime} \mathrm{OL}$ | Low Level Output Current | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {DD }}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {SS }}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.64 |  |  |  |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

DC Electrical Characteristics CD4093BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $+85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 1.0 |  |  | 1.0 |  | 7.5 | $\mu \mathrm{A}$ |
|  |  |  |  | 2.0 |  |  | 2.0 |  | 15.0 | $\mu \mathrm{A}$ |
|  |  |  |  | 4.0 |  |  | 4.0 |  | 30.0 | $\mu \mathrm{A}$ |
| VoL | Low Level Output Voltage | $V_{\text {IN }}=V_{\text {DD }}, l_{\text {O }} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| V OH | High Level Output Voltage | $V_{\text {IN }}=V_{\text {SS }},\left\|I_{O}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| $\mathrm{V}_{\mathrm{T}-}$ | Negative-Going Threshold Voltage (Any Input) | $1 \mathrm{O} \mathrm{I}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.5 \mathrm{~V}$ | 1.3 | 2.25 | 1.5 | 1.8 | 2.25 | 1.5 | 2.30 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9 \mathrm{~V}$ | 2.85 | 4.5 | 3.0 | 4.1 | 4.5 | 3.0 | 4.65 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | 4.35 | 6.75 | 4.5 | 6.3 | 6.75 | 4.5 | 6.9 | v |
| $\mathrm{V}_{\mathrm{T}+}$ | Positive-Going Threshold Voltage (Any Input) | $\left\|I_{O}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ | 2.75 | 3.6 | 2.75 | 3.3 | 3.5 | 2.65 | 3.5 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{O}=1 \mathrm{~V}$ | 5.5 | 7.15 | 5.5 | 6.2 | 7.0 | 5.35 | 7.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 8.25 | 10.65 | 8.25 | 9.0 | 10.5 | 8.1 | 10.5 | V |
| $\mathrm{v}_{\mathrm{H}}$ | Hysteresis $\left(V_{T+}-V_{T-}\right)$ <br> (Any Input) | $V_{D D}=5 \mathrm{~V}$ | 0.5 | 2.35 | 0.5 | 1.5 | 2.0 | 0.35 | 2.0 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 1.0 | 4.3 | 1.0 | 2.2 | 4.0 | 0.70 | 4.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 1.5 | 6.3 | 1.5 | 2.7 | 6.0 | 1.20 | 6.0 | $v$ |
| IOL | Low Level Output Current | $V_{\text {IN }}=V_{\text {DD }}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{\text {IN }}=V_{\text {SS }}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | -8.0 | -8.8 |  | -2.4 |  | mA |
| IN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} C, C_{L}=50 \rho F, R_{L}=200 \mathrm{k}$, Input $t_{t}, t_{f}=20 \mathrm{~ns}$, unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL, tPLH | Propagation Delay Time | $V_{D D}=5 \mathrm{~V}$ |  | 300 | 600 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 120 | 300 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 | 240 | ns |
| ${ }^{\text {t }} \mathrm{HL}$, tTLH | Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 90 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| CIN | Average Input Capacitance |  |  | 5.0 | 7.5 | pF |
| CPD | Power Dissipation Capacitance |  |  | 24 |  | pF |

Typical Applications

## Gated Oscillator



Assume $t_{1}+t_{2} \gg t_{P H L}+t_{\text {PLH }}$ then:
$t_{0}=R C \ln \left[V_{D D} / V_{T-}\right]$
$t_{1}=R C \ln \left[\left(V_{D D}-V_{T-}\right) /\left(V_{D D}+V_{T+}\right)\right]$
$t_{2}=R C \ln \left[V_{T+} / V_{T-}\right]$
$f=\frac{1}{t_{1}+t_{2}}=\frac{1}{R C \ln \frac{\left(V_{T+}\right)\left(V_{D D}-V_{T-}\right)}{\left(V_{T_{-}}\right)\left(V_{D D}-V_{T+}\right)}}$


## Gated One-Shot

(a) Negative-Edge Triggered

(b) Positive-Edge Triggered


## Typical Performance Characteristics



Input and Output Characteristics


## AC Test Circuits and Switching Time Waveforms



National

# CD4094BM/CD4094BC 8-Bit Shift Register/Latch with TRI-STATE ${ }^{\circledR}$ Outputs 

## General Description

The CD4094BM/CD4094BC consists of an 8-bit shift register and a TRI-STATE ${ }^{\oplus} 8$-bit latch. Data is shifted serially through the shift register on the positive transition of the clock. The output of the last stage $\left(Q_{S}\right)$ can be used to cascade several devices. Data on the $Q_{S}$ output is transferred to a second output, $Q_{S}^{\prime}$, on the following negative clock edge.
The output of each stage of the shift register feeds a latch, which latches data on the negative edge of the STROBE input. When STROBE is high, data propagates through the latch to TRI-STATE output gates. These gates are enabled when OUTPUT ENABLE is taken high. TRI-STATE is a registered trademark of National Semiconductor Corp.

## Features

Wide supply voltage range 3.0 V to 18 V

- High noise immunity
- Low power TTL compatibility
fan out of 2 driving 74L or 1 driving 74LS
- TRI-STATE outputs


## Connection Diagram



## Block or Logic Diagram



## Absolute Maximum Ratings

(Notes 1 and 2)
$\begin{array}{lr}V_{D D} \text { Supply Voltage } & -0.5 \text { to }+18 \mathrm{~V}_{D C} \\ \mathrm{~V}_{\text {IN }} \text { Input Voltage } & -0.5 \text { to } \mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}_{D C} \\ \mathrm{~T}_{S} \text { Storage Temperature Range } & -65^{\circ} \mathrm{C} \text { to }+150^{\circ} \mathrm{C} \\ \mathrm{P}_{D} \text { Package Dissipation } & 500 \mathrm{~mW} \\ \mathrm{~T}_{\mathrm{L}} \text { Lead Temperature (Soldering, } 10 \text { seconds) } & 300^{\circ} \mathrm{C}\end{array}$

Recommended Operating Conditions
(Note 2)

| $V_{D D} D C$ Supply Voltage | +3.0 to $+15 V_{D C}$ |
| :--- | ---: |
| $V_{I N}$ Input Voltage | 0 to $V_{D D} V_{D C}$ |
| $T_{A}$ Operating Temperature Range |  |
| CD4094BM | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD4094BC | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

DC Electrical Characteristics CD4094BM (Note 2)

| Parameter | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IDD Quiescent Device Current | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 5.0 \\ & 10 \\ & 20 \end{aligned}$ |  |  | $\begin{aligned} & 5.0 \\ & 10 \\ & 20 \end{aligned}$ |  | $\begin{aligned} & 150 \\ & 300 \\ & 600 \end{aligned}$ | $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ |
| Vol Low Level Output Voltage | $\left.\begin{array}{l} V_{D D}=5.0 \mathrm{~V} \\ V_{D D}=10 \mathrm{~V} \\ V_{D D}=15 \mathrm{~V} \end{array}\right\}\|\mathrm{IO}\| \leqslant 1.0 \mu \mathrm{~A}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \\ & 0.05 \end{aligned}$ |  | $\begin{aligned} & 0 \\ & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & 0.05 \\ & 0.05 \\ & 0.05 \end{aligned}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \\ & 0.05 \end{aligned}$ | $\begin{aligned} & V \\ & V \\ & V \end{aligned}$ |
| $\mathrm{V}_{\mathrm{OH}}$ High Level Output Voltage | $\left.\begin{array}{l} V_{D D}=5.0 \mathrm{~V} \\ V_{D D}=10 \mathrm{~V} \\ V_{D D}=15 \mathrm{~V} \end{array}\right\}\left\|\mathrm{l}_{\mathrm{O}}\right\| \leqslant 1 \mu \mathrm{~A}$ | $\begin{gathered} 4.95 \\ 9.95 \\ 14.95 \end{gathered}$ |  | $\begin{gathered} 4.95 \\ 9.95 \\ 14.95 \end{gathered}$ | $\begin{gathered} 5.0 \\ 10.0 \\ 15.0 \end{gathered}$ |  | $\begin{gathered} 4.95 \\ 9.95 \\ 14.95 \end{gathered}$ |  | $\begin{aligned} & V \\ & V \\ & V \end{aligned}$ |
| VIL Low Level Input Voltage | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V} \text { or } 13.5 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ | $\begin{aligned} & V \\ & V \\ & V \end{aligned}$ |
| $V_{I H}$ High Level Input Voltage | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V} \text { or } 13.5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 3.5 \\ 7.0 \\ 11.0 \end{gathered}$ |  | $\begin{gathered} 3.5 \\ 7.0 \\ 11.0 \end{gathered}$ |  |  | 3.5 7.0 11.0 |  | $\begin{aligned} & V \\ & v \\ & v \end{aligned}$ |
| IOL Low Level Output Current | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.4 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 0.64 \\ 1.6 \\ 4.2 \end{gathered}$ |  | 0.51 1.3 3.4 | $\begin{gathered} 0.88 \\ 2.25 \\ 8.8 \end{gathered}$ |  | 0.36 0.9 2.4 |  | mA <br> $m A$ <br> mA |
| $\mathrm{l}_{\mathrm{OH}}$ High Level Output Current | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=4.6 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{O}=113.5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} -0.64 \\ -1.6 \\ -4.2 \end{gathered}$ |  | $\begin{gathered} -0.51 \\ -1.3 \\ -3.4 \end{gathered}$ | $\begin{gathered} 0.88 \\ 2.55 \\ 8.8 \end{gathered}$ |  | $\begin{gathered} -0.36 \\ -0.9 \\ -2.4 \end{gathered}$ |  | $m A$ <br> mA <br> mA |
| IIN Input Current | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} -0.1 \\ 0.1 \end{gathered}$ |  |  | $\begin{gathered} -0.1 \\ 0.1 \end{gathered}$ |  | $\begin{array}{r} -1.0 \\ 1.0 \end{array}$ | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |

DC Electrical Characteristics CD4094BC (Note 2)

| Parameter | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IDD Quiescent Device Current | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 20 \\ & 40 \\ & 80 \end{aligned}$ |  |  | $\begin{aligned} & 20 \\ & 40 \\ & 80 \end{aligned}$ |  | $\begin{aligned} & 150 \\ & 300 \\ & 600 \end{aligned}$ | $\mu \mathrm{A}$ $\mu \mathrm{A}$ $\mu \mathrm{A}$ |
| Vol Low Level Output Voltage | $\left.\begin{array}{l} \mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{array}\right\}\left\|I_{\mathrm{O}}\right\| \leqslant 1.0 \mu \mathrm{~A}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \\ & 0.05 \end{aligned}$ |  | $\begin{aligned} & 0 \\ & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & 0.05 \\ & 0.05 \\ & 0.05 \end{aligned}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \\ & 0.05 \end{aligned}$ | $\begin{aligned} & V \\ & v \\ & v \end{aligned}$ |
| $\mathrm{V}_{\mathrm{OH}}$ High Level Output Voltage | $\left.\begin{array}{l} V_{D D}=5.0 \mathrm{~V} \\ V_{D D}=10 \mathrm{~V} \\ V_{D D}=15 \mathrm{~V} \end{array}\right\}\|I \mathrm{O}\| \leqslant 1 \mu \mathrm{~A}$ | $\begin{gathered} 4.95 \\ 9.95 \\ 14.95 \end{gathered}$ |  | $\begin{gathered} 4.95 \\ 9.95 \\ 14.95 \end{gathered}$ | $\begin{gathered} 5.0 \\ 10.0 \\ 15.0 \end{gathered}$ |  | $\begin{gathered} 4.95 \\ 9.95 \\ 14.95 \end{gathered}$ |  | $\begin{aligned} & V \\ & V \\ & V \end{aligned}$ |
| VIL Low Level Input Voltage | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V} \text { or } 13.5 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ | $\begin{aligned} & V \\ & V \\ & v \end{aligned}$ |
| $V_{\mathrm{IH}}$ High Level Input Voltage | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V} \text { or } 13.5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 3.5 \\ 7.0 \\ 11.0 \end{gathered}$ |  | $\begin{gathered} 3.5 \\ 7.0 \\ 11.0 \end{gathered}$ |  |  | $\begin{gathered} 3.5 \\ 7.0 \\ 11.0 \end{gathered}$ |  | $\begin{aligned} & V \\ & V \\ & V \end{aligned}$ |
| Iol Low Level Output Current | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.4 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 0.52 \\ 1.3 \\ 3.6 \\ \hline \end{gathered}$ |  | $\begin{gathered} 0.44 \\ 1.1 \\ 3.0 \end{gathered}$ | $\begin{gathered} 0.88 \\ 2.25 \\ 8.8 \\ \hline \end{gathered}$ |  | $\begin{gathered} 0.36 \\ 0.9 \\ 2.4 \\ \hline \end{gathered}$ |  | mA <br> mA <br> mA |


| Parameter | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IOH High Level Output Current | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=4.6 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{O}=113.5 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & -0.52 \\ & -1.3 \\ & -3.6 \end{aligned}$ |  | $\begin{gathered} -0.44 \\ -1.1 \\ -3.0 \end{gathered}$ | $\begin{gathered} 0.88 \\ 2.55 \\ 8.8 \end{gathered}$ |  | $\begin{gathered} -0.36 \\ -0.9 \\ -2.4 \end{gathered}$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \\ & \mathrm{~mA} \end{aligned}$ |
| IIN Input Current | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} -0.3 \\ 0.3 \end{gathered}$ |  |  | $\begin{gathered} -0.3 \\ 0.3 \end{gathered}$ |  | $\begin{gathered} -1.0 \\ 1.0 \end{gathered}$ | $\mu \mathrm{A}$ $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$

|  |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {PHL }}, \mathrm{t}_{\text {PLH }}$ | Propagation Delay Clock to $Q_{\text {S }}$ | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 300 \\ 125 \\ 95 \end{gathered}$ |  | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\mathrm{PHL}}, \mathrm{t}_{\text {PLH }}$ | Propagation Delay Clock to Q's | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 230 \\ 110 \\ 75 \end{gathered}$ |  | ns <br> ns <br> ns |
| $t_{\text {PHL }}, \mathrm{t}_{\text {PLH }}$ | Propagation Delay Clock to Parallel Out | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 420 \\ & 195 \\ & 135 \end{aligned}$ |  | ns <br> ns <br> ns |
| $t_{\text {PHL }}, t_{\text {PLH }}$ | Propagation Delay Strobe to Parallel Out | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 290 \\ & 145 \\ & 100 \end{aligned}$ |  | ns <br> ns <br> ns |
| ${ }^{\text {tpHZ }}$ | Propagation Delay High Level to High Impedance | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 140 \\ 75 \\ 55 \end{gathered}$ |  |  |
| ${ }_{\text {t }}^{\text {PLZ }}$ | Propagation Delay Low Level to High Impedance | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 225 \\ 95 \\ 70 \end{gathered}$ |  | ns <br> ns <br> ns |
| $t_{\text {PZH }}$ | Propagation Delay High Impedance to High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 225 \\ 95 \\ 70 \end{gathered}$ |  | ns <br> ns <br> ns |
| $t_{\text {PZL }}$ | Propagation Delay High Impedance to Low Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 140 \\ & 75 \\ & 55 \end{aligned}$ |  | ns <br> ns <br> ns |
| $t_{\text {THL }}, \mathrm{t}_{\text {TLH }}$ | Transition Time | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 100 \\ 50 \\ 40 \end{gathered}$ |  | ns ns ns |
| tsu | Set-up Time Data to Clock | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 60 \\ & 30 \\ & 20 \end{aligned}$ |  | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{r}, t_{f}$ | Maximum Clock Rise and Fall Time | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 15 \\ & 5.0 \\ & 5.0 \end{aligned}$ |  |  | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \\ & \mu \mathrm{~S} \end{aligned}$ |
| $t_{\text {PC }}$ | Minimum Clock Pulse Width | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | , | $\begin{gathered} 100 \\ 50 \\ 40 \end{gathered}$ |  | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {PS }}$ | Minimum Strobe Pulse Width | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 100 \\ 40 \\ 35 \end{gathered}$ |  | ns <br> ns <br> ns |
| $f_{\text {MAX }}$ | Maximum Clock Frequency | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 2.5 \\ & 5.0 \\ & 6.0 \end{aligned}$ |  | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Any Input |  | 5.0 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $V_{S S}=0 \mathrm{~V}$ unless otherwise specified.

## Timing Diagram



## Test Circuits and Timing Diagrams for TRI-STATE ${ }^{\circledR}$


$t_{\text {PZL }}, t_{\text {PLZ }}$

$\mathbf{t}_{\mathbf{P Z H}}, \mathbf{t}_{\mathrm{PHZ}}$

| Clock | Output Enable | Strobe | Data | Parallel Outputs |  | Serial Outputs |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Q1 | $Q_{N}$ | Qs* | Q's |
| $\Gamma$ | 0 | X | X | $\mathrm{Hi}-\mathrm{Z}$ | Hi-Z | Q7 | No Chg. |
| L | 0 | X | X | Hi-Z | Hi-Z | No Chg. | Q7 |
| $\Gamma$ | 1 | 0 | X | No Chg. | No Chg. | Q7 | No Chg. |
| $\Gamma$ | 1 | 1 | 0 | 0 | $Q_{N}-1$ | Q7 | No Chg. |
| $\Gamma$ | 1 | 1 | 1 | 1 | $Q_{N}-1$ | Q7 | No Chg. |
| L | 1 | 1 | 1 | No Chg. | No Chg. | No Chg. | Q7 |

X = Don't Care
*At the positive clock edge, information in the 7th shift register stage is transferred to Q8 and QS.

## CD4099BM/CD4099BC 8-Bit Addressable Latch

## General Description

The CD4099B is an 8-bit addressable latch with three address inputs (AO-A2), an active low enable input (E), active high clear input (CL), a data input (D), and eight outputs (Q0-Q7).

Data is entered into a particular bit in the latch when that bit is addressed by the address inputs and the enable ( E ) is low. Data entry is inhibited when enable $(\bar{E})$ is high.
When clear (CL) and enable ( $\overline{\mathrm{E}}$ ) are high, all outputs are low. When clear (CL) is high and enable ( $\bar{E}$ ) is low, the channel demultiplexing occurs. The bit that is addressed has an active output which follows the data input while all unaddressed bits are held low. When operating in the addressable latch mode ( $\bar{E}=C L=$ low), changing more than one bit of the address could impose a transient wrong address. Therefore, this should only be done while in the memory mode ( $\mathrm{E}=$ high, $\mathrm{CL}=$ low).

Features

- Wide supply voltage range
- High noise immunity
- Low power TTL compatibility
fan out of 2 driving 74L or 1 driving 74LS
- Serial to parallel capability
- Storage register capability
- Random (addressable) data entry
- Active high demultiplexing capability
- Common active high clear


## Connection Diagram

## Truth Table

| MODE SELECTION |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| $\bar{E}$ | CL | ADDRESSED <br> LATCH | UNADDRESSED LATCH | MODE |
| L | L | Follows Data | Holds Previous Data | Addressable Latch |
| H | L | Holds Previous Data | Holds Previous Data | Memory |
| L | H | Follows Data | Reset to "0" | Demultiplexer |
| H | H | Reset to "0" | Reset to " 0 " | Clear |

## Absolute Maximum Ratings

(Notes 1 and 2)
$V_{D D}$ DC Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{S}}$ Storage Temperature Range
PD Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds) $\quad 300^{\circ} \mathrm{C}$

Recommended Operating Conditions
(Note 2)

| $V_{D D}$ DC Supply Voltage | 3.0 to $15 V_{D C}$ |
| :--- | ---: |
| $V_{I N}$ Input Voltage | 0 to $V_{D D} V_{D C}$ |
| $T_{A}$ Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD4099BM | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

DC Electrical Characteristics cD4099bm (Note 2)

| Parameter |  | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| $I_{\text {DD }}$ | Quiescent |  | $\mathrm{V}_{\text {DD }}=5.0 \mathrm{~V}$ |  | 5.0 |  | 0.02 | 5.0 |  | 150 | $\mu \mathrm{A}$ |
|  | Device Current | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  | 0.02 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  | 0.02 | 20 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level | $\left\|\mathrm{l}_{0}\right\| \leqslant 1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  | Output Voltage | $V_{D D}=5.0 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level | $\left\|l_{0}\right\| \leqslant 1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  | Output Voltage | $V_{D D}=5.0 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL | Low Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  | Input Voltage | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  | Input Voltage | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| IOL | Low Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  | Output Current | $\mathrm{V}_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| $\mathrm{I}_{\mathrm{OH}}$ | High Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  | Output Current | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| $\mathrm{I}_{\text {IN }}$ | Input Current | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{I N}=0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=15 \mathrm{~V} \end{aligned}$ |  | -0.1 0.1 |  | $-10^{-5}$ $10^{-5}$ | -0.1 0.1 |  | $\begin{array}{r} -1.0 \\ 1.0 \end{array}$ | $\mu \mathrm{A}$ $\mu \mathrm{A}$ |

## DC Electrical Characteristics CD4099BC (Note 2)

| Parameter |  | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| $I_{\text {DD }}$ | Quiescent Device Current |  | $V_{D D}=5.0 \mathrm{~V}$ |  | 20 |  | 0.02 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.02 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 0.02 | 80 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\left\|l_{0}\right\| \leqslant 1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5.0 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\left\|l_{0}\right\| \leqslant 1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5.0 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $\mathrm{V}_{\mathrm{IL}}$ | Low Level Input Voltage |  |  |  |  | 2.25 |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $V_{1 H}$ |  |  |  |  | 3.5 |  |  |  |  | V |
|  | Input Voltage | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |

## DC Electrical Characteristics (cont'd) CD4099BC (Note 2)

| Parameter |  | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| lOL | Low Level |  | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  | Output Current | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| $\mathrm{IOH}^{\text {O }}$ | High Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  | Output Current | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| In | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ |  | -0.30 |  | $-10^{-5}$ | -0.30 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.30 |  | $10^{-5}$ | 0.30 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} C, C_{L}=50 p F, R_{L}=200 \mathrm{~K}$, Input $t_{r}=t_{f}=20$ ns, unless otherwise noted.

| Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {PHL }}, \mathrm{t}_{\text {PLH }}$ Propagation Delay Date to Output | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 200 \\ & 75 \\ & 50 \end{aligned}$ | $\begin{aligned} & 400 \\ & 150 \\ & 100 \end{aligned}$ |  |
| $t_{\text {PLH }}, \mathrm{t}_{\text {PHL }}$ Propagation Delay Enable to Output | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 200 \\ 80 \\ 60 \end{gathered}$ | $\begin{aligned} & 400 \\ & 160 \\ & 120 \end{aligned}$ |  |
| $\mathrm{t}_{\text {PHL }} \quad$ Propagation Delay Clear to Output | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 175 \\ & 80 \\ & 65 \end{aligned}$ | $\begin{aligned} & 350 \\ & 160 \\ & 130 \end{aligned}$ | ns <br> ns <br> ns |
| $\mathrm{t}_{\text {PLH }}, \mathrm{t}_{\text {PHL }}$ Propagation Delay Address to Output | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 225 \\ 100 \\ 75 \end{gathered}$ | $\begin{aligned} & 450 \\ & 200 \\ & 150 \end{aligned}$ | ns ns ns |
| $\mathrm{t}_{\text {THL }}, \mathrm{t}_{\text {TLH }}$ Transition Time (Any Output) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 50 \\ & 40 \end{aligned}$ | $\begin{gathered} 200 \\ 100 \\ 80 \end{gathered}$ | ns <br> ns ns |
| $t_{\text {WH }}, T_{\text {WL }}$ Minimum Data Pulse Width | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 100 \\ 50 \\ 40 \end{gathered}$ | $\begin{gathered} 200 \\ 100 \\ 80 \end{gathered}$ | ns <br> ns <br> ns |
| $t_{\text {WH }}, t_{\text {WL }}$ Minimum Address Pulse Width | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 200 \\ & 100 \\ & 65 \end{aligned}$ | $\begin{aligned} & 400 \\ & 200 \\ & 125 \end{aligned}$ | ns <br> ns ns |
| $t_{\text {WH }} \quad$ Minimum Clear Pulse Width | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 75 \\ & 40 \\ & 25 \end{aligned}$ | $\begin{aligned} & 150 \\ & 75 \\ & 50 \end{aligned}$ |  |
| $\mathrm{t}_{\text {SU }} \quad$ Minimum Set-Up Time Data to E | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 40 \\ & 20 \\ & 15 \end{aligned}$ | $\begin{aligned} & 80 \\ & 40 \\ & 30 \end{aligned}$ | ns <br> ns <br> ns |
| $t_{H} \quad$ Minimum Hold Time Data to E | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 60 \\ & 30 \\ & 25 \end{aligned}$ | $\begin{gathered} 120 \\ 60 \\ 50 \end{gathered}$ | ns <br> ns <br> ns |
| tsu Minimum Set-Up Time Address to E | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} -15 \\ 0 \\ 0 \end{gathered}$ | $\begin{aligned} & 50 \\ & 30 \\ & 20 \end{aligned}$ | ns <br> ns <br> ns |
| $\mathrm{t}_{\mathrm{H}} \quad$ Minimum Hold Time Address to E | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & -50 \\ & -20 \\ & -15 \end{aligned}$ | $\begin{gathered} 15 \\ 10 \\ 5 \end{gathered}$ | ns <br> ns ns |
| $\mathrm{C}_{\mathrm{PD}} \quad$ Power Dissipation Capacitance | Per Package (Note 3) |  | 100 |  | pF |
| $\mathrm{C}_{\text {IN }} \quad$ Input Capacitance | Any Input |  | 5.0 | 7.5 | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: Dynamic power dissipation ( $P_{D}$ ) is given by: $P_{D}=\left(C_{P D}+C_{L}\right) V_{C C}{ }^{2} f+P_{Q}$; where $C_{L}=$ load capacitance; $f=$ frequency of operation; for further details, see application note AN-90, "54C/74C Family Characteristics".


## Switching Time Waveforms



## CD40106BM/CD40106BC Hex Schmitt Trigger

## General Description

The CD40106B Hex Schmitt Trigger is a monolithic complementary MOS (CMOS) integrated circuit constructed with N and P -channel enhancement transistors. The positive and negative-going threshold voltages, $\mathrm{V}_{\mathrm{T}+}$ and $\mathrm{V}_{\mathrm{T}_{-} \text {, show }}$ low variation with respect to temperature $\left(\operatorname{typ} 0.0005 \mathrm{~V} /{ }^{\circ} \mathrm{C}\right.$ at $\left.\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}\right)$, and hysteresis, $V_{T+}-V_{T-} \geq 0.2 V_{D D}$ is guaranteed.

All inputs are protected from damage due to static discharge by diode clamps to $\mathrm{V}_{\mathrm{DD}}$ and $\mathrm{V}_{\mathrm{SS}}$.

## Features

■ Wide supply voltage range 3 V to 15 V

- High noise immunity 0.7 VDD.(typ.)
- Low power fan out of 2

TTL compatibility driving 74L
or 1 driving
74LS

- Hysteresis $0.4 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
0.2 VDD guaranteed
- Equivalent to MM54C14/MM74C14
- Equivalent to MC14584B


## Schematic Diagram



## Connection Diagram

## Dual-In-Line Package



Switching Time Waveforms


## Absolute Maximum Ratings

(Notes 1 and 2)
$V_{\text {DD }}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
$T_{S}$ Storage Temperature Range
PD Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
-0.5 to $+18 V_{D C}$
-0.5 to $V_{D D}+0.5 V_{D C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW $300^{\circ} \mathrm{C}$
(Note 2)
$V_{D D}$ de Supply Voltage
$V_{\text {IN }}$ Input Voltage
$T_{A}$ Operating Temperature Range CD40106BM
CD40106BC

3 to $15 V_{D C}$
0 to $V_{D D} V_{D C}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## DC Electrical Characteristics CD40106BM (Note 2)

|  | PARAMETER | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 1.0 |  |  | 1.0 |  | 30 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 2.0 |  |  | 2.0 |  | 60 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 4.0 |  |  | 4.0 |  | 120 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $\\|_{0} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | v |
| $\mathrm{VOH}^{\text {O }}$ | High Level Output Voltage | $\\|_{0} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| $V_{T-}$ | Negative-Going Threshold Voltage | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.5 \mathrm{~V}$ | 0.7 | 2.0 | 0.7 | 1.4 | 2.0 | 0.7 | 2.0 | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9 \mathrm{~V}$ | 1.4 | 4.0 | 1.4 | 3.2 | 4.0 | 1.4 | 4.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=13.5 \mathrm{~V}$ | 2.1 | 6.0 | 2.1 | 5.0 | 6.0 | 2.1 | 6.0 | $v$ |
| $\mathrm{V}_{\mathrm{T}+}$ | Positive-Going Threshold Voltage | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ | 3.0 | 4.3 | 3.0 | 3.6 | 4.3 | 3.0 | 4.3 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1 \mathrm{~V}$ | 6.0 | 8.6 | 6.0 | 6.8 | 8.6 | 6.0 | 8.6 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 9.0 | 12.9 | 9.0 | 10.0 | 12.9 | 9.0 | 12.9 | $v$ |
| $V_{H}$ | Hysteresis ( $\mathrm{V}_{\mathrm{T}+}-\mathrm{V}_{\mathrm{T}-}$ ) | $V_{D D}=5 \mathrm{~V}$ | 1.0 | 3.6 | 1.0 | 2.2 | 3.6 | 1.0 | 3.6 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 2.0 | 7.2 | 2.0 | 3.6 | 7.2 | 2.0 | 7.2 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 3.0 | 10.8 | 3.0 | 5.0 | 10.8 | 3.0 | 10.8 | V |
| IOL | Low Level Output Current |  |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | $-2.25$ |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| İN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V}$ |  | -0.10 |  | $-10^{-5}$ | -0.10 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V}$ |  | 0.10 |  | $10^{-5}$ | 0.10 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $V_{S S}=0 V$ unless otherwise specified.
Note 3: CPD determines the no load ac power consumption of any CMOS device. For complete explanation, see 54C/74C Family Characteristics application note-AN-90.

## DC Electrical Characteristics CD40106BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $+85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 4.0 |  |  | 4.0 |  | 30 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 8.0 |  |  | 8.0 |  | 60 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 16.0 |  |  | 16.0 |  | 120 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\mathrm{lIO}_{\mathrm{O}}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | v |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\\|_{0} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| $V_{T-}$ | Negative-Going Threshold | $V_{D D}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=4.5 \mathrm{~V}$ | 0.7 | 2.0 | 0.7 | 1.4 | 2.0 | 0.7 | 2.0 | V |
|  | Voltage | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9 \mathrm{~V}$ | 1.4 | 4.0 | 1.4 | 3.2 | 4.0 | 1.4 | 4.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | 2.1 | 6.0 | 2.1 | 5.0 | 6.0 | 2.1 | 6.0 | v |
| $V_{T+}$ |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ | 3.0 | 4.3 | 3.0 | 3.6 | 4.3 | 3.0 | 4.3 | V |
|  | Voltage | $V_{D D}=10 \mathrm{~V}, V_{O}=1 \mathrm{~V}$ | 6.0 | 8.6 | 6.0 | 6.8 | 8.6 | 6.0 | 8.6 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 9.0 | 12.9 | 9.0 | 10.0 | 12.9 | 9.0 | 12.9 | v |
| $\mathrm{V}_{\mathrm{H}}$ | Hysteresis ( $\mathrm{V}_{\mathrm{T}+}-\mathrm{V}_{\mathrm{T}_{-}}$) | $V_{D D}=5 \mathrm{~V}$ | 1.0 | 3.6 | 1.0 | 2.2 | 3.6 | 1.0 | 3.6 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 2.0 | 7.2 | 2.0 | 3.6 | 7.2 | 2.0 | 7.2 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 3.0 | 10.8 | 3.0 | 5.0 | 10.8 | 3.0 | 10.8 | $v$ |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 | 1 | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{0}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.30 |  | $-10^{-5}$ | -0.30 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.30 |  | $10^{-5}$ | 0.30 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}, \mathrm{t}_{\mathrm{r}}$ and $\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :--- | :--- | :--- | :--- | :--- | :---: | :---: |
| tPHL or tPLH | Propagation Delay Time From | $V_{D D}=5 \mathrm{~V}$ |  | 220 | 400 | ns |
|  | Input To Output | $V_{D D}=10 \mathrm{~V}$ |  | 80 | 200 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 70 | 160 | ns |
| tTHL or tTLH | Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 50 | 100 | ns |  |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| CIN | Average Input Capacitance | Any Input | 5 | 7.5 | pF |  |
| CPD | Power Dissipation Capacitance | Any Gate (Note 3) |  | 14 |  | pF |

## Low Power Oscillator


$\mathrm{t}_{1} \approx \mathrm{RC} \ln \frac{\mathrm{V}_{\mathrm{T}_{+}}}{\mathrm{V}_{\mathrm{T}-}}$
$t_{2} \approx R C \ln \frac{V_{D D}-V_{T-}}{V_{D D}-V_{T+}}$
$f \approx \frac{1}{R C \ln \frac{V_{T+}\left(V_{D D}-V_{T-}\right)}{V_{T-}\left(V_{D D}-V_{T+}\right)}}$
Note: The equations assume
$\mathrm{t}_{1}+\mathrm{t}_{2} \gg \mathrm{t}_{\mathrm{pHL}}+\mathrm{t}_{\mathrm{pLH}}$

## Typical Performance Characteristics

Typical Transfer Characteristics


Guaranteed
Trip Point Range




## CD40160BM/CD40160BC Decade Counter with Asynchronous Clear CD40161BM/CD40161BC Binary Counter with Asynchronous Clear CD40162BM/CD40162BC Decade Counter with Synchronous Clear CD40163BM/CD40163BC Binary Counter with Synchronous Clear

## General Description

These (synchronous presettable up) counters are monolithic complementary MOS (CMOS) integrated circuits constructed with N - and P -channel enhancement mode transistors. They feature an internal carry look-ahead for fast counting schemes and for cascading packages without additional gating.
A low level at the load input disables counting and causes the outputs to agree with the data input after the next positive clock edge. The clear function for the CD40162B and CD40163B is synchronous and a low level at the clear input sets all four outputs low after the next positive clock edge. The clear function for the CD40160B and CD40161B is asynchronous and a low level at the clear input sets all four outputs low, regardless of the state of the clock.

Counting is enabled when both count enable inputs are high. Input T is fed forward to also enable the carry out. The carry output is a positive pulse with a duration approximately equal to the positive portion of $Q_{A}$ and can
be used to enable successive cascaded stages. Logic transitions at the enable P or T inputs can occur when the clock is high or low.

## Features

- Wide supply voltage range
3.0 V to 15 V
- High noise immunity
0.45 VDD (typ.)
- Low power TTL
fan out of 2 driving 74L compatibility or 1 driving 74LS
- Internal look-ahead for fast counting schemes
- Carry output for N -bit cascading
- Load control line
- Synchronously programmable
- Equivalent to MC14160B, MC14161B, MC14162B, MC14163B
- Equivalent to MM74C160, MM74C161, MM74C162, MM74C163


## Connection Diagram



TOP VIEW

Absolute Maximum Ratings
(Notes 1 and 2)
$V_{D D}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
$P_{D}$ Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
-0.5 to $+18 V_{D C}$
-0.5 to $V_{D D}+0.5 V_{D C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$300^{\circ} \mathrm{C}$
(Note 2)
$V_{D D}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD40XXXBM CD40XXXBC

3 to $15 \mathrm{~V} D C$ 0 to $V_{D D} V_{D C}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ , $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

DC Electrical Characteristics CD40160BC/CD40162BC/CD40163BC (Note 2)


DC Electrical Characteristics CD40160BM/CD40162BM/CD40163BM (Note 2)

|  | PARAMETER | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| ${ }^{\prime}$ DD | Quiescent Device Current | $V_{D D}=5 \mathrm{~V}$ |  | 20 |  |  | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  |  | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  |  | 80 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {OL }}$ | Low Level Output Voltage | $\mid \mathrm{I}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
| VOH | High Level Output Voltage | $\mid \mathrm{I}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
|  | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  |  | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | V |

DC Electrical Characteristics (Cont'd.) CD40160BC/CD40161BC/CD40162BC/CD40163BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| $\mathrm{V}_{\text {IH }}$ | High Level Input Voltage |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 |  |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | $v$ |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=4.6 \mathrm{~V}$ |  |  |  | -0.88 |  |  |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | $-1.3$ |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| In | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.30 |  | $-10^{-5}$ | -0.30 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.30 |  | $10^{-5}$ | 0.30 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $V_{S S}=O V$ unless otherwise specified.
Note 3: CPD determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note, AN-90.

AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{~K}$, unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL or tPLH | Propagation Delay Time From Clock to Q | $V_{D D}=5 \mathrm{~V}$ |  | 250 | 400 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 100 | 160 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 | 130 | ns |
| tPHL or tPLH | Propagation Delay Time From | $V_{D D}=5 \mathrm{~V}$ |  | 290 | 450 | ns |
|  | Clock to Carry Out | $V_{D D}=10 \mathrm{~V}$ |  | 120 | 190 | ns |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 100 | 160 | ns |
| tPHL or TPLH | Propagation Delay Time From T | $V_{\text {DD }}=5 \mathrm{~V}$ |  | 180 | 290 | ns |
|  | Enable to Carry Out | $V_{D D}=10 \mathrm{~V}$ |  | 70 | 130 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 60 | 110 | ns |
| tPHL | Propagation Time From Clear to Q (CD40160B, CD40161B Only) | $V_{\text {DD }}=5 \mathrm{~V}$ |  | 190 | 300 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 80 | 150 | ns |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 70 | 120 | ns |
| ${ }^{\text {t }} \mathrm{SU}$ | Minimum Time Prior to Clock that Data or Load must be Present | $V_{D D}=5 \mathrm{~V}$ |  | 120 |  | ns |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}$ |  | 30 |  | ns |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 25 |  | ns |
| ${ }^{\text {t }} \mathrm{SU}$ | Minimum Time Prior to Clock that Enable P or T must be Present | $V_{D D}=5 \mathrm{~V}$ |  | 170 | 280 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 70 | 120 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 60 | 100 | ns |
| ${ }^{\text {t }}$ SU | Minimum Time Prior to Clock that | $V_{D D}=5 \mathrm{~V}$ |  | 120 | 190 | ṇs |
|  | Clear must be Present (CD40162B, | $V_{\text {DD }}=10 \mathrm{~V}$ |  | 50 | 80 | ns |
|  | CD40163B Only) | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 40 | 70 | ns |
| tWL or tWH | Maximum Clock Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 125 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 45 | 90 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 35 | 70 | ns |
| ${ }^{\text {t }}$ RCL, ${ }^{\text {t }}$ FCL | Maximum Clock Rise or Fall Time | $V_{D D}=5 \mathrm{~V}$ |  |  | 15 | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  |  | 5.0 | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  |  | 5.0 | $\mu \mathrm{s}$ |
| ${ }^{\mathrm{f}} \mathrm{CL}$ | Maximum Clock Frequency | $V_{D D}=5 \mathrm{~V}$ | 2 | 4 |  | MHz |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 5.5 | 11 |  | MHz |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 7 | 14 |  | MHz |
| ${ }^{\text {t }}$ HL or tTLH | Transition Time | All Outputs |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| $\mathrm{CIN}^{\text {I }}$ | Average Input Capacitance | Any Input |  | 5.0 | 7.5 | pF |
| CPD | Power Dissipation Capacity | (Note 3) |  | 95 |  | pF |



Logic Waveforms


## Switching Time Waveforms


tphl CLEAR FOR CD40160B AND CD40161B ONLY
Note 1: All input pulses are from generators having the following characteristics: $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$ PRR $\leq$ 1 MHz duty cycle $\leq 50 \%, Z_{\text {OUT }} \approx 50 \Omega$. Note 2: All times are measured from $50 \%$ to $50 \%$.

## Cascading Packages



## CD40174BM/CD40174BC Hex D Flip-Flop CD40175BM/CD40175BC Quad D Flip-Flop

## General Description

The CD40174B consists of six positive-edge triggered D-type flip-flops; the true output from each flip-flop are externally available. The CD40175B consists of four positive-edge triggered D-type flip-flops; both the true and complement outputs from each flip-flop are externally available.

All flip-flops are controlled by a common clock and a common clear. Information at the D inputs meeting the set-up time requirements is transferred to the Q outputs on the positive-going edge of the clock pulse. The clearing operation, enabled by a negative pulse at Clear input, clears all Q outputs to logical " 0 " and Q 's (CD40175B only) to logical "1,"

All inputs are protected from static discharge by diode clamps to $\mathrm{V}_{\mathrm{DD}}$ and $\mathrm{V}_{\mathrm{SS}}$.

## Features

- Wide supply voltage range

3 V to 15 V
a High noise immunity

- Low power TTL compatibility

Equivalent to MC14174B, MC14175B

- Equivalent to MM74C174, MM74C175


## Connection Diagrams

CD40174B

Dual-In-Line Package


## Truth Table

| INPUTS |  |  | OUTPUTS |  |
| :---: | :---: | :---: | :---: | :---: |
| CLEAR | CLOCK | D | Q | $\overline{\mathbf{Q}}^{*}$ |
| L | X | X | L | H |
| H | $\uparrow$ | H | H | L |
| H | $\uparrow$ | L | L | H |
| H | H | X | NC | NC |
| H | L | X | NC | NC |

[^21]CD40175B
Dual-In-Line Package


Switching Time Waveforms

$\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$
Absolute Maximum Ratings
(Notes 1 and 2)
$V_{\text {DD }}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
PD Package Dissipation
${ }^{T} L$ Lead Temperature, (Soldering, 10 seconds)

## DC Electrical Characteristics CD40174Bm/CD40175BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 1.0 \\ & 2.0 \\ & 4.0 \end{aligned}$ |  |  | 1.02.04.0 |  | $\begin{aligned} & 30 \\ & 60 \\ & 120 \end{aligned}$ |  | $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ |
|  |  |  |  |  |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $\begin{aligned} & \left\|I_{O}\right\|<1 \mu \mathrm{~A} \\ & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4.95 \\ & 9.95 \\ & 14.95 \end{aligned}$ |  |  |  |  |  |  |  |  |
|  |  |  |  | 0.05 |  |  | 0.05 |  | 0.05 | V |  |
|  |  |  |  | 0.05 |  |  | 0.05 |  | 0.05 | V |  |
|  |  |  |  | 0.05 |  |  | 0.05 |  | 0.05 | V |  |
| VOH | High Level Output Voltage | $\begin{aligned} & I_{O} \mid<1 \mu \mathrm{~A} \\ & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  |  |  |  |  |  |  |  |  |
|  |  |  |  |  | 4.95 | 5 |  | 4.95 |  | v |  |
|  |  |  |  |  | 9.95 | 10 |  | 9.95 . |  | V |  |
|  |  |  |  |  | 14.95 | 15 |  | 14.95 |  | V |  |
| VIL | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | V |  |
|  |  | $\mathrm{V}_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  |  | 3.0 |  | 3.0 | V |  |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | V |  |
| $\mathrm{V}_{\text {IH }}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | V |  |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 |  |  | 7.0 |  | V |  |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | V |  |
| ${ }^{\mathrm{I}} \mathrm{OL}$ | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |  |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |  |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 | - | mA |  |
| ${ }^{\mathrm{I} O H}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | - 0.51 | -0.88 |  | -0.36 |  | mA |  |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | $-2.25$ |  | -0.9 |  | mA |  |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |  |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ |  |  | -1.0 | $\mu \mathrm{A}$ |  |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ |  |  | 1.0 | $\mu \mathrm{A}$ |  |

## DC Electrical Characteristics CD40174BC/CD40175BC/ (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 4 |  |  | 4 |  | 30 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 8 |  |  | 8 |  | 60 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 16 |  |  | 16 |  | 120 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | v |
| V OH | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | $v$ |
| VIL | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  |  | 3.0 |  | 3.0 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | v |
| $\mathrm{V}_{\text {IH }}$ | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 |  |  | 7.0 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | v |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $v_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{v}$ | 1.3 . |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 3.6 |  | 8.0 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current. | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.52 |  | -0.41 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | -8.0 | -8.8 |  | -2.4 |  | mA |
| IN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.30 |  | $-10^{-5}$ | -0.30 |  | $-1.0$ | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  |  |  | $10^{-5}$ | 0.30 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}$, and $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL or tPLH | Propagation Delay Time to a Logical | $V_{D D}=5 \mathrm{~V}$ |  | 190 | 300 | ns |
|  | "0" or Logical " 1 " from Clock to Q | $V_{D D}=10 \mathrm{~V}$ |  | 75 | 110 | ns |
|  | or $\overline{\mathrm{Q}}$ (CD40175 Only) | $V_{D D}=15 \mathrm{~V}$ |  | 60 | 90 | ns |
| tPHL | Propagation Delay Time to a Logical | $V_{D D}=5 \mathrm{~V}$ |  | 180 | 300 | ns |
|  | " 0 " from Clear to Q | $V_{D D}=10 \mathrm{~V}$ |  | 70 | 110 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 60 | 90 | ns |
| tPLH | Propagation Delay Time to a Logical | $V_{D D}=5 \mathrm{~V}$ |  | 230 | 400 | ns |
|  | "1" from Clear to $\overline{\mathrm{Q}}$ (CD40175 Only) | $V_{D D}=10 \mathrm{~V}$ |  | 90 | 150 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 75 | 120 | ns |
| ${ }^{\text {t }}$ U | Time Prior to Clock Pulse that Data | $V_{D D}=5 \mathrm{~V}$ | 100 | 45 |  | ns |
|  | must be Present | $V_{D D}=10 \mathrm{~V}$ | 40 | 16 |  | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 35 | 13 |  | ns |
| ${ }^{\text {t }} \mathrm{H}$ | Time after Clock Pulse that Data | $V_{D D}=5 \mathrm{~V}$ |  | -11 | 0 | ns |
|  | must be Held | $V_{D D}=10 \mathrm{~V}$ |  | -4 | 0 | ns |
|  |  | $V_{D D}=15 V$ |  | -3 | 0 | ns |
| ${ }^{\mathrm{t}} \mathrm{THL}$ or tTLH | Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| ${ }^{\text {t WH, }}{ }^{\text {t }}$ WL | Minimum Clock Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 130 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 45 | 100 | n; |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| ${ }^{t}$ WL | Minimum Clear Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 120 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 45 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| $t_{\text {RCL }}$ | Maximum Clock Rise Time | $V_{D D}=5 \mathrm{~V}$ | 15 | 450 |  | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 5.0 | 125 |  | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 5.0 | 125 |  | $\mu \mathrm{s}$ |
| $\mathrm{t}_{\mathrm{fCL}}$ | Maximum Clock Fall Time | $V_{D D}=5 \mathrm{~V}$ | 15 | 50 |  | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 5.0 | 50 |  | $\mu \mathrm{s}$ |
|  | , | $V_{D D}=15 \mathrm{~V}$ | 5 | 50 |  | $\mu \mathrm{s}$ |
| ${ }^{\mathrm{f}} \mathrm{CL}$ | Maximum Clock Frequency | $V_{D D}=5 \mathrm{~V}$ | 2.0 | 3.5 |  | MHz |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 5.0 | 10 |  | MHz |
|  | , | $V_{D D}=15 \mathrm{~V}$ | 6.0 | 12 |  | MHz |
| CIN | Input Capacitance | Clear Input, |  | 10 |  | pF |
|  |  | Other Input |  | 5.0 | 7.5 | pF |
| CPD | Power Dissipation | Per Package, (Note 3) |  | 130 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: CPD determines the no load ac power consumption of any CMOS device. For complete explanation, see 54C/74C Family Characteristics application note, AN-90.

## CD40192BM/CD40192BC Synchronous 4-Bit Up/Down Decade Counter CD40193BM/CD40193BC Synchronous 4-Bit Up/Down Binary Counter

## General Description

These up/down counters are monolithic complementary MOS (CMOS) integrated circuits. The CD40192BM and CD40192BC are BCD counters. While the CD40193BM and CD40193BC are binary counters.

Counting up and counting down is performed by two count inputs, one being held high while the other is clocked. The outputs change on the positive-going transition of this clock.

These counters feature preset inputs that are enabled when load is a logical " 0 " and a clear which forces all outputs to " 0 " when it is at logical " 1 ". The counters also have carry and borrow outputs so that they can be cascaded using no external circuitry.

## Features

- Wide supply voltage range

3 V to 15 V

- High noise immunity
0.45 VDD (typ.)
- Low power TTL compatibility
fan out of 2
driving 74L
or 1 driving 74LS
- Carry and borrow outputs for easy expansion to N -bit by cascading
- Asynchronous clear
- Equivalent to

MM54C192/MM74C192 and MM54C193/MM74C193

All inputs are protected against damage due to static discharge by clamps to $\mathrm{V}_{\mathrm{DD}}$ and $\mathrm{V}_{\mathrm{SS}}$.

## Connection Diagram



## Cascading Packages



## Absolute Maximum Ratings

(Notes 1 and 2)
$V_{\text {DD }}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
$P_{D}$ Package Dissipation
$T_{L}$ Lead Temperature, (Soldering, 10 seconds)
-0.5 to $+18 \mathrm{~V}_{\mathrm{DC}}$
-0.5 to $V_{D D}+0.5 V_{D C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW $300^{\circ} \mathrm{C}$

Recommended Operating Conditions
(Note 2)

| $V_{\text {DD }}$ dc Supply Voltage | 3 to $15 V_{D C}$ |
| :--- | ---: |
| $V_{\text {IN }}$ Input Voltage | 0 to $V_{D D} V_{D C}$ |
| $T_{A}$ Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD40192BM, CD40193BM | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

DC Electrical Characteristics (Note 2) CD40192BM/CD40193BM


## DC Electrical Characteristics (Note 2) CD40192BC/CD40193BC



AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k} \Omega$, Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified.

| PARAMETER |  | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPLH | Propagation Delay Time From Count Up | $V_{D D}=5 \mathrm{~V}$ |  | 250 | 400 | ns |
| or | Or Count Down To Q | $V_{D D}=10 \mathrm{~V}$ |  | 100 | 160 | ns |
| tpHL |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 | 130 | ns |
| tPLH | Propagation Delay Time From Count Up | $V_{D D}=5 \mathrm{~V}$ |  | 120 | 200 | ns |
| or | To Carry | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 80 | ns |
| tPHL |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 65 | ns |
| tPLH | Propagation Delay Time From Count | $V_{D D}=5 \mathrm{~V}$ |  | 120 | 200 | ns |
| or | Down To Borrow | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 80 | ns |
| tPHL |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 65 | ns |
| $\mathrm{t}_{\text {SU }}$ | Time Prior To Load That Data Must | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 160 | ns |
|  | Be Present | $V_{D D}=10 \mathrm{~V}$ |  | 30 | 50 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 25 | 40 | ns |
| tPHL | Propagation Delay Time From Clear | $V_{D D}=5 \mathrm{~V}$ |  | 130 | 220 | ns |
|  | To Q | $V_{D D}=10 \mathrm{~V}$ |  | 60 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 50 | 80 | ns |
| tPLH | Propagation Delay Time From Load | $V_{D D}=5 \mathrm{~V}$ |  | 300 | 480 | ns |
| or | To Q | $V_{D D}=10 \mathrm{~V}$ |  | 120 | 190 | ns |
| tPHL |  | $V_{D D}=15 \mathrm{~V}$ |  | 95 | 150 | ns |
| ${ }^{\text {t }}$ LH | Output Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
| or |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
| ${ }^{\text {t }}$ HL |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| ${ }^{f} \mathrm{CL}$ | Maximum Count Frequency | $V_{D D}=5 \mathrm{~V}$ | 2.5 | 4 |  | MHz |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 6 | 10 |  | MHz |
|  |  | $V_{D D}=15 \mathrm{~V}$. | 7.5 | 12.5 |  | MHz |
| $\mathrm{t}_{\mathrm{RCL}}$ | Maximum Count Rise Or Fall Time | $V_{D D}=5 \mathrm{~V}$ | 15 |  |  | $\mu \mathrm{s}$ |
| or |  | $V_{D D}=10 \mathrm{~V}$ | 5 |  |  | $\mu \mathrm{s}$ |
| $\mathrm{t}_{\mathrm{fCL}}$ |  | $V_{D D}=15 \mathrm{~V}$ | 1 |  |  | $\mu \mathrm{s}$ |
| $\mathrm{t}_{\mathrm{WH}}$, $\mathrm{W}_{\text {W }}$ | Minimum Count Pulse Width | $V_{D D}=5 V$ |  | 120 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 35 | 80 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 28 | 65 | ns |
| ${ }^{\text {t }} \mathrm{WH}$ | Minimum Clear Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 300 | 480 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 120 | 190 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 95 | 150 | ns |
| twL | Minimum Load Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 160 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 | 65 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 32 | 55 | ns |
| $\mathrm{CIN}^{\text {I }}$ | Average Input Capacitance | Load and Data Inputs (A,B,C,D) |  | 5 | 7.5 | pF |
|  |  | Count Up, Count |  | 10 | 15 | pF |
|  |  | Down and Clear |  |  |  |  |
| CPD | Power Dissipation Capacity | (Note 3) |  | 100 |  | pF |

[^22]
## Schematic Diagrams



CD40193BM/CD40193BC Synchronous 4-Bit Up/Down Binary Counter


Sequence:

1. Clear outputs to zero.
2. Load (preset) to BCD seven.
3. Count up to eight, nine, carry, zero, one and two.
4. Count down to one, zero, borrow, nine, eight and seven.

CD40192BM/CD40192BC


## CD4503BM/CD4503BC Hex Non-Inverting TRI-STATE ${ }^{\text {® }}$ Buffer

## General Description

The CD4503B is a hex non-inverting TRISTATE ${ }^{\circledR}$ buffer with high output current sink and source capability. TRISTATE outputs make it useful in bus-oriented applications. Two separate disable inputs are provided. Buffers 1 through 4 are controlled by the disable 4 input. Buffers 5 and 6 are controlled by the disable 2 input. A high level on either disable input will cause those gates on its control line to go into a high impedance state.

## Features

- Wide supply voltage range
$3.0 V_{D C}$ to $18 V_{D C}$
- TRI-STATE outputs
- Symmetrical turn on/turn off delays
- Symmetrical output rise and fall times
- Pin-for-pin replacement for MM80C97 and MC14503

TRI-STATE is a registered trademark of National Semiconductor Corp.

Schematic and Connection Diagrams


Truth Table

| In | Disable <br> Input | Out |
| :---: | :---: | :---: |
| 0 | 0 | 0 |
| 1 | 0 | 1 |
| $X$ | 1 | TRI-STATE |

X = Don't Care

## Absolute Maximum Ratings

(Notes 1 and 2)
VDD - Supply Voltage
VIN - Input Voltage
TS - Storage Temperature Range
PD - Power Dissipation
$\mathrm{T}_{\mathrm{L}}$ - Lead Temperature (soldering, 10 seconds) $300^{\circ} \mathrm{C}$
-0.5 V to +18 V
-0.5 V to +0.5 V
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW

Recommended Operating Conditions
(Note 2)
VDD - Supply Voltage
3 V to 15 V
$\mathrm{T}_{\mathrm{A}}$ - Operating Temperature Range CD4503BM
CD4503BC
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## DC Electrical Characteristics CD4503BM (Note 2)

| Parameter | Conditions | $-55^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Typ | Max | Min | Max |  |
| IDD Quiescent Device Current | $V_{D D}=5 \mathrm{~V}$ |  | 1 |  |  | 1 |  | 30 | $\mu \mathrm{A}$ |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 2 |  |  | 2 |  | 60 | $\mu \mathrm{A}$ |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 4 |  |  | 4 |  | 120 | $\mu \mathrm{A}$ |
| VOL Low Level Output Voltage | $V_{\text {IN }}=V_{\text {DD }}$ or 0 |  |  |  |  |  |  |  |  |
|  | $V_{D D}=5 V$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | $V_{D D}=15 V$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ High Level Output Voltage | $V_{\text {IN }}=V_{\text {DD }}$ or 0 |  |  |  |  |  |  |  |  |
|  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL Low Level Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{O}}=4.5 \mathrm{~V} \text { or } 0.5 \mathrm{~V} \end{aligned}$ |  | 1.5 | . | 2.25 | 1.5 |  | 1.5 | V |
|  | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{O}}=9.0 \mathrm{~V} \text { or } 1.0 \mathrm{~V} \end{aligned}$ |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | V |
|  | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, \\ & V_{O}=13.5 \mathrm{~V} \text { or } 1.5 \mathrm{~V} \end{aligned}$ |  | 4.0 | $i$ | 6.75 | 4.0 |  | 4.0 | V |
| VIH High Level Input Voltage | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{O}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V} \end{aligned}$ | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  | $\begin{aligned} & V_{D D}=10 \mathrm{~V} \\ & V_{O}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V} \end{aligned}$ | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V} \text { or } 13.5 \mathrm{~V} \end{aligned}$ | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| IOL Low Level Output Current | $\mathrm{V}_{\mathrm{DD}}=4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{OL}}=0.4 \mathrm{~V}$ |  |  |  | 2.55 | . | 1.60 |  | mA |
|  | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OL}}=0.4 \mathrm{~V}$ | 3.00 |  | 2.40 | 2.75 |  | 1.75 |  | mA |
|  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OL}}=0.5 \mathrm{~V}$ | 7.85 |  | 6.35 | 7.00 |  | 4.45 |  | mA |
|  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{OL}}=1.5 \mathrm{~V}$ | 19.95 |  | 16.10 | 25.00 |  | 11.30 |  | mA |
| IOH High Level Output Current | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{OH}}=4.6 \mathrm{~V}$ | -1.28 |  | -1.02 | -1.76 |  | -0.72 |  | mA |
|  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OH}}=9.5 \mathrm{~V}$ | -3.20 |  | -2.60 | -4.5 |  | -1.8 |  | mA |
|  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{OH}}=13.5 \mathrm{~V}$ | -8.20 |  | -6.80 | -17.6 |  | -4.8 |  | mA |
| IOZ TRI-STATE® Leakage Current | $V_{D D}=15 \mathrm{~V}$ |  | $\pm 0.1$ |  | $\pm 10^{-4}$ | $\pm 0.1$ |  | $\pm 1.0$ | $\mu \mathrm{A}$ |
| IIN Input Current | $V_{D D}=15 \mathrm{~V}$ |  | $\pm 0.1$ |  | $\pm 10^{-4}$ | $\pm 0.1$ |  | $\pm 1.0$ | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

| Parameter | Conditions | $-40^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Typ | Max | Min | Max |  |
| IDD Quiescent Device Cumer | $V_{D D}=5 \mathrm{~V}$ |  |  |  | 4 |  |  | 30 | $\mu \mathrm{A}$ |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 8 |  | 8 |  |  | 60 | $\mu \mathrm{A}$ |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 16 |  | 16 |  |  | 120 | $\mu \mathrm{A}$ |
| VOL Low Level Outpui Voltage | $V_{\text {IN }}=V_{\text {JD }}$ or 0 |  |  |  |  |  |  |  |  |
|  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 | . | 0.05 | V |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| VOH High Level Output Voltage | $V_{\text {IN }}=V_{\text {DD }}$ or 0 |  |  |  |  |  |  |  |  |
|  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 |  |  | 4.95 |  | V |
|  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 |  |  | 9.95 |  | V |
|  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 |  |  | 14.95 |  | V |
| VIL Low Level Input Voltage | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, \\ & V_{O}=4.5 \mathrm{~V} \text { or } 0.5 \mathrm{~V} \end{aligned}$ |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  | $\begin{aligned} & V D D=1 \mathrm{CV} \\ & V_{O}=9.0 \mathrm{~V} \text { or } 1.0 \mathrm{~V} \end{aligned}$ |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | V |
|  | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, \\ & V_{O}=13.5 \mathrm{~V} \text { or } 1.5 \mathrm{~V} \end{aligned}$ |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| VIH High Level.Input Voltage | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{O}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V} \end{aligned}$ | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  | $\begin{aligned} & \mathrm{VDD}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V} \end{aligned}$ | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, \\ & V_{O}=1.5 \mathrm{~V} \text { or } 13.5 \mathrm{~V} \end{aligned}$ | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| IOL Low Level Output Current | $\mathrm{V}_{\mathrm{DD}}=4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{OL}}=0.4 \mathrm{~V}$ | 2.30 |  | 1.95 | 2.65 |  | 1.60 |  | mA |
|  | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OL}}=0.4 \mathrm{~V}$ | 2.5 |  | 2.10 | 2.75 |  | 1.75 |  | mA |
|  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OL}}=0.5 \mathrm{~V}$ | 6.5 |  | 5.45 |  |  | 4.45 |  | mA |
|  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{OL}}=1.5 \mathrm{~V}$ | 16.50 |  | 13.80 | 25.00 |  | 11.30 |  | mA |
| IOH High Level Output Current | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{OH}}=4.6 \mathrm{~V}$. | -1.04 |  | -0.88 | -1.76 |  | -0.7 |  | mA |
|  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OH}}=9.5 \mathrm{~V}$ | -2.60 |  | -2.2 | -4.50 |  | -1.8 |  | mA |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{OH}}=13.5 \mathrm{~V}$ | -7.2 |  | -6.0 | -17.6 |  | -4.8 |  | mA |
| ITL TRI-STATE ${ }^{\text {® }}$ Leakage Current | $V_{D D}=15 \mathrm{~V}$ |  | $\pm 0.3$ |  | $\pm 10^{-4}$ | $\pm 0.3$ |  | $\pm 1.0$ | $\mu \mathrm{A}$ |
| IIN Input Current | $V_{D D}=15 \mathrm{~V}$ |  | $\pm 0.3$ |  | $\pm 10^{-5}$ | $\pm 0.3$ |  | $\pm 1.0$ |  |

## AC Electrical Characteristics CD4503B

$T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, R_{L}=200 \mathrm{k} \Omega$, Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified.

|  | Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL, TPLH | Propagation Delay Time | $V_{D D}=5 \mathrm{~V}$ |  | 75 | 100 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 35 | 40 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 25 | 30 | ns |
| tPLZ, tPHZ | Propagation Delay Time, Logical Level to High Impedance State | $V_{D D}=5 \mathrm{~V}$ |  | 80 | 125 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 | 90 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 35 | 70 | ns |
| tPZL, tPZH | Propagation Delay Time, High Impedance State to Logical Level | $V_{D D}=5 \mathrm{~V}$ |  | 95 | 175 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 | 80 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 35 | 70 | ns |
| ${ }^{\text {t }}$ L H | Output Fise Time | $V_{D D}=5 \mathrm{~V}$ |  | 45 | 80 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 23 | 40 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 18 | 35 | ns |
| ${ }^{\text {t }} \mathrm{HL}$ | Output fall Time | $V_{D D}=5 \mathrm{~V}$ |  | 45 |  | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 23 | 40 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 18 | 35 | ns |

## AC Test Circuits and Switching Time Waveforms

${ }^{\text {tPHL }}$, tPLH


CMOS to CMOS

${ }^{t} P L Z$ and ${ }^{t} P Z L$

tPLZ

${ }^{\text {tPZL }}$


Note: Delays measured with input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}} \leqslant 20 \mathrm{~ns}$.

## CD4510BM/CD4510BC BCD Up/Down Counter CD4516BM/CD4516BC Binary Up/Down Counter

## General Description

The CD4510BM/CD4510BC and CD4516BM/CD4516BC are monolithic CMOS up/down counters which count in BCD and binary, respectively.
The counters count up when the up/down input is at logical " 1 " and vice versa. A logical " 1 " preset enable signal allows information at the parallel inputs to preset the counters to any state synchronously with the clock. The counters are advanced one count at the positivegoing edge ofthe clock if the carry in, preset enable, and reset inputs are at logical " 0 ". Advancement is inhibited when any of these three inputs are at logical " 1 ". The carry out signal is normally at logical " 1 " state and goes to logical " 0 " when the counter reaches its maximum count in the "up" mode or its minimum count in the "down" mode, provided the carry input is at logical " 0 " state. The counters are cleared asynchronously by applying a logical " 1 " voltage level at the reset input.

All inputs are protected against static discharge by diode clamps to both $V_{D D}$ and $V_{S S}$.

## Features

| Wide supply voltage range | 3.0 V to 15 V |
| :--- | ---: |
| - High noise immunity | $0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.) |
| Low power TTL  <br> compatibility fan out of 2 driving 74L <br> or 1 driving 74LS  |  |
| Parallel load "jam" inputs |  |
| Low quiescent power dissipation <br> (typ.) @ $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ |  |
| Motorola MC14510, MC14516 second source |  |



## Truth Table

TOP VIEW

| CLOCK | RESET | PRESET <br> ENABLE | CARRY <br> IN | UP/DOWN | OUTPUT <br> FUNCTION |
| :---: | :---: | :---: | :---: | :---: | :--- |
| $\times$ | 1 | X | X | X | Reset to zero |
| X | 0 | 1 | X | X | Set to P1, P2, P3, P4 |
| $\sim$ | 0 | 0 | 0 | 1 | Count up |
| $\sim$ | 0 | 0 | 0 | 0 | Count down |
| $\sim$ | 0 | 0 | X | X | No change |
| $\times$ | 0 | 0 | 1 | X | No change |

[^23]Absolute Maximum Ratings
(Notes 1 and 2)
$V_{D D}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
$P_{D}$ Package Dissipation
TL Lead Temperature (Soldering, 10 seconds)
-0.5 V to +18 V
-0.5 V to $\mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$300^{\circ} \mathrm{C}$
(Note 2)
$V_{D D}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4510BM, CD4516BM
CD4510BC, CD4516BC

3 V to 15 V 0 to $V_{D D}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## DC Electrical Characteristics CD4510BM/CD4516BM (Note 2)

|  | PARAMETER | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current | $V D D=5 V$ |  | 5 |  | 0.05 | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  | 0.1 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}$ |  | 20 |  | 0.15 | 20 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $V_{\text {IH }}=V_{\text {DD }}, V_{\text {IL }}=0 \mathrm{~V}, \\|_{\mathrm{O}} \mid<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{\text {IH }}=V_{\text {DD }}, V_{\text {IL }}=0 \mathrm{~V}, \\|_{\mathrm{O}} \mathrm{L}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 | . | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level Input Voltage | ${ }^{\prime} \mathrm{I}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| V/H | High Level Input Voltage | $\left\|\mathrm{I}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| ${ }^{1} \mathrm{OL}$ | Low Level Output Current | $V_{\text {IH }}=V_{\text {DD }}, V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.8 |  | 0.36 |  | mA |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.0 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 7.8 |  | 2.4 |  | mA |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{I H}=V_{D D}, V_{I L}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.8 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.0 |  | -0.9 |  | $m A$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | $-7.8$ |  | -2.4 |  | mA |
| $I_{\text {IN }}$ | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | $-1.0$ | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

DC Electrical Characteristics CD4510BC/CD4516BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 20 |  | 0.05 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.1 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 0.15 | 80 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $V_{I H}=V_{D D}, V_{I L}=0 V, \\|_{O} \mid<1 \mu A$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{I H}=V_{\text {DD }}, V_{I L}=0 V, \\|_{O} \mid<1 \mu A$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |

## DC Electrical Characteristics (Cont'd.) CD4510BC/CD4516BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| VIL | Low Level Input Voltage |  | $\mid 1 \mathrm{O}^{\prime}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {DD }}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $V_{\text {IH }}$ | High Level Input Voltage | $\\|_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| ${ }^{\text {I OL }}$ | Low Level Output Current | $V_{\text {IH }}=V_{\text {DD }}, V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.8 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.0 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 7.8 |  | 2.4 |  | mA |
| $\mathrm{IOH}^{\prime}$ | High Level Output Current | $V_{\text {IH }}=V_{\text {DD }}, V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.8 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | $-1.3$ |  | -1.1 | -2.0 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | $-3.6$ |  | -3.0 | $-7.8$ |  | -2.4 |  | $m \mathrm{~A}$ |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | 1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: Devices should not be connected while power is "ON."

## Switching Time Waveforms



AC Electrical Characteristics CD4510BM/CD4510BC, CD4516BM/CD4516BC
$\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}, \mathrm{t}_{\mathrm{r}} \mathrm{CL}=\mathrm{t}_{\mathrm{f} C \mathrm{C}}=\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CLOCKED OPERATION |  |  |  |  |  |  |
| tPHL, tPLH | Propagation Delay Time Clock to O Outputs | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & \hline 220 \\ & 100 \\ & 80 \end{aligned}$ | $\begin{aligned} & \hline 500 \\ & 200 \\ & 180 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| tPHL, tPLH | Propagation Delay Time Clock to Carry Output | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 315 \\ & 130 \\ & 100 \end{aligned}$ | $\begin{aligned} & 630 \\ & 260 \\ & 200 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{t}_{\text {THL, }} \mathrm{t}$ LLH | Transition Time Q and Carry Outputs | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 50 \\ & 40 \end{aligned}$ | $\begin{aligned} & 200 \\ & 100 \\ & 80 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| tWL, twh | Minimum Clock Pulse Width | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 160 \\ & 65 \\ & 50 \end{aligned}$ | $\begin{aligned} & 315 \\ & 130 \\ & 100 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{tr}_{\mathrm{CL}}, \mathrm{t}_{\mathrm{f}} \mathrm{CL}$ | Maximum Clock Rise and Fall Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 15 \\ & 15 \\ & 15 \end{aligned}$ |  |  | $\begin{aligned} & \mu \mathrm{s} \\ & \mu \mathrm{~s} \\ & \mu \mathrm{~s} \end{aligned}$ |
| ${ }^{\text {tsu }}$ | Minimum Carry, In Set-Up Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 40 \\ & 35 \end{aligned}$ | $\begin{aligned} & 220 \\ & 80 \\ & 70 \end{aligned}$ | ns <br> ns <br> ns |
| ${ }_{\text {t }}$ U | Minimum Up/Down Set-Up Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 200 \\ & 70 \\ & 60 \end{aligned}$ | $\begin{aligned} & 420 \\ & 170 \\ & 150 \end{aligned}$ | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| ${ }^{\mathrm{f}} \mathrm{CL}$ | Maximum Clock Frequency | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 3.8 \\ & 5.0 \end{aligned}$ | $\begin{aligned} & 3.1 \\ & 7.6 \\ & 10.0 \end{aligned}$ |  | MHz <br> MHz <br> MHz |
| $\begin{aligned} & \mathrm{C}_{\mathrm{IN}} \\ & \mathrm{C}_{\mathrm{PD}} \end{aligned}$ | Input Capacitance <br> Power Dissipation Capacitance <br> (Note 4) | Any Input <br> Per Package, |  | 5 <br> 65 | 7.5 | pF <br> pF |

RESET/PRESET ENABLE OPERATION


Note 4: Dynamic power dissipation ( $P_{D}$ ) is given by: $P_{D}=\left(C P D+C_{L}\right) V_{D D}{ }^{2} f+P_{Q}$; where $C_{L}=$ load capacitance; $f=$ frequency of operation; $P_{Q}=$ Quiescent Power Dissipation. For further details, see application note AN-90, " $54 \mathrm{C} / 74 \mathrm{C}$ Family characteristics."

Parallel Clocking


Ripple Clocking



FIGURE 1. CD4510

*Flip-flop toggles at the positive-going edge of clock $(C)$ if Toggle Enable
(TE) is at logical " 1 " and Preset Enable (PE) is at logical " 0 "

FIGURE 2. CD4516


CD4516BM/CD4516BC


## CD4511BM/CD4511BC BCD-to-7 Segment Latch/Decoder/Driver

## General Description

The CD4511BM/CD4511BC BCD-to-seven segment latch/ decoder/driver is constructed with complementary MOS (CMOS) enhancement mode devices and NPN bipolar output drivers in a single monolithic structure. The circuit provides the functions of a 4-bit storage latch, an 8421 BCD-to-seven segment decoder, and an output drive capability. Lamp test (LT), blanking (BI), and latch enable (LE) inputs are used to test the display, to turn-off or pulse modulate the brightness of the display, and to store a BCD code, respectively. It can be used with seven-segment light emitting diodes (LED), incandescent, fluorescent, gas discharge, or liquid crystal readouts either directly or indirectly.

Applications include instrument (e.g., counter, DVM, etc.) display driver, computer/calculator display driver, cockpit display driver, and various clock, watch, and timer uses.

## Features

- Low logic circuit power dissipation
- High current sourcing outputs (up to 25 mA )
. Latch storage of code
- Blanking input
- Lamp test provision
- Readout blanking on all illegal input combinations
a Lamp intensity modulation capability
- Time share (multiplexing) facility

Equivalent to Motorola MC14511

## Connection Diagram



Segment Identification


## Truth Table

| INPUTS |  |  |  |  |  |  | OUTPUTS |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| LE | $\overline{B 1}$ | $\overline{\text { LT }}$ | D | C | B | A | a | b | c | d | e | $f$ | g | DISPLAY |
| $x$ | X | 0 | $x$ | $x$ | $x$ | $x$ | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 8 |
| X | 0 | 1 | X | X | X | x | 0 | 0 | 0 | 0 | 0 | 0 | 0 |  |
| 0 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 |
| 0 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 1 |
| 0 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 2 |
| 0 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 3 |
| 0 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 4 |
| 0 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 5 |
| 0 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 6 |
| 0 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 7 |
| 0 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 8 |
| 0 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | - 1 | 1 | 9 |
| 0 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |  |
| 0 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |  |
| 0 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |  |
| 0 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |  |
| 0 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |  |
| 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |  |
| 1 | 1 | 1 |  |  |  | X |  |  |  | * |  |  |  | * |

$X=$ Don't care
*Depends upon the BCD code applied during the 0 to 1 transition of LE.
(Notes 1 and 2)
$V_{\text {DD }}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
$T_{S}$ Storage Temperature Range
$P_{D}$ Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
-0.5 V to +18 V
-0.5 V to $\mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$300^{\circ} \mathrm{C}$
$V_{D D}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4510BM, CD4516BM CD4510BC, CD4516BC

3 V to 15 V 0 to $V_{D D}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## DC Electrical Characteristics CD4511BM

| PARAMETER | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  |  | $+25^{\circ} \mathrm{C}$ |  |  | $+125^{\circ} \mathrm{C}$ |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX |  |
| Output Voltage | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4.1 \\ & 9.1 \\ & 14.1 \end{aligned}$ |  | $\begin{aligned} & 0.01 \\ & 0.01 \end{aligned}$ |  | 0 | 0.01 | $\begin{aligned} & 4.1 \\ & 9.1 \\ & 14.1 \end{aligned}$ |  | 0.05 | V |
| Logical "0" |  |  |  |  |  | 0 | 0.01 |  |  | 0.05 | V |
| Level (VOUT) |  |  |  |  |  | 0 |  |  |  |  | V |
| Output Voltage <br> Logical "1" <br> Level (VOUT) | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  |  |  | 4.1 | 4.57 |  |  |  |  | V |
|  |  |  |  |  | 9.1 | 9.58 |  |  |  |  | V |
|  |  |  |  |  | 14.1 | 14.59 |  |  |  |  | V |
| Low Level Input Voltage (VIL) | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, V_{O U T}=3.8 \mathrm{~V} \text { or } 0.5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O U T}=8.8 \mathrm{~V} \text { or } 1.0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{\text {OUT }}=13.8 \mathrm{~V} \text { or } 1.5 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 3.0 \\ & 4.0 \end{aligned}$ |  | 2 | 1.5 |  |  | 1.5 | V |
|  |  |  |  |  |  | 4 | 3.0 |  |  | 3.0 | V |
|  |  |  |  |  |  | 6 | 4.0 |  |  | 4.0 | V |
| High Level Input Voltage ( $\mathrm{V}_{\text {IH }}$ ) | $\begin{aligned} & V_{D D}=5 \mathrm{~V}, V_{\text {OUT }}=0.5 \mathrm{~V} \text { or } 3.8 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.0 \mathrm{~V} \text { or } 8.8 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.5 \mathrm{~V} \text { or } 13.8 \mathrm{~V} \end{aligned}$ | 3.5 |  |  | 3.5 | 3 |  | 3.5 |  |  | V |
|  |  | 7.0 |  |  | 7.0 | 6 |  | 7.0 |  |  | V |
|  |  | 11.0 |  |  | 11.0 | 9 |  | 11.0 |  |  | V |
| Output (Source) <br> Drive Voltage $\left(\mathrm{VOH}_{\mathrm{OH}}\right)$ | $\begin{array}{ll} V_{D D}=5 \mathrm{~V}, & I O H=0 \mathrm{~mA} \\ \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V}, & I O H=5 \mathrm{~mA} \\ \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V}, \quad 1 O H=10 \mathrm{~mA} \\ \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V}, \quad 1 O H=15 \mathrm{~mA} \\ \mathrm{~V}_{D D}=5 \mathrm{~V}, \quad 1 O H=20 \mathrm{~mA} \\ V_{D D}=5 \mathrm{~V}, \quad 1 O H=25 \mathrm{~mA} \end{array}$ | 4.1 |  |  | 4.1 | 4.57 |  | 4.1 |  |  | V |
|  |  |  |  |  |  | 4.24 |  |  |  |  | V |
|  |  | 3.9 |  |  | 3.9 | 4.12 |  | 3.5 |  |  | V |
|  |  |  |  |  |  | 3.94 |  |  |  |  | v |
|  |  | 3.4 |  |  | 3.4 | 3.75 |  | 3.0 |  |  | V |
|  |  |  |  |  |  | 3.54 |  |  |  |  | V |
|  | $V_{\text {DD }}=10 \mathrm{~V}, \mathrm{I}^{\circ} \mathrm{OH}=0 \mathrm{~mA}$ | 9.1 |  |  | 9.1 | 9.58 |  | 9.1 |  |  | V |
|  |  |  |  |  |  | 9.26 |  |  |  |  | v |
|  |  | 9.0 |  |  | 9.0 | 9.17 |  | 8.6 |  |  | V |
|  | $\begin{aligned} & V_{D D}=10 \mathrm{~V}, \mathrm{IOH}^{2}=10 \mathrm{~mA} \\ & V_{D D}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=15 \mathrm{~mA} \end{aligned}$ |  |  |  |  | 9.04 |  |  |  |  | V |
|  | $\begin{aligned} & V_{D D}=10 \mathrm{~V}, \mathrm{IOH}_{\mathrm{O}}=20 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=25 \mathrm{~mA} \end{aligned}$ | 8.6 |  |  | 8.6 | 8.9 |  | 8.2 |  |  | v |
|  |  |  |  |  |  | 8.75 |  |  |  |  | V |
|  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{IOH}=0 \mathrm{~mA}$ | 14.1 |  |  | 14.1 | 14.59 |  | 14.1 |  |  | $v$ |
|  | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, \mathrm{IOH}_{\mathrm{OH}}=5 \mathrm{~mA} \\ & V_{D D}=15 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=10 \mathrm{~mA} \end{aligned}$ |  |  |  |  | 14.27 |  |  |  |  | V |
|  |  | 14.0 |  |  | 14.0 | 14.18 |  | 13.6 |  |  | V |
|  | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, \mathrm{IOH}_{\mathrm{OH}}=10 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=15 \mathrm{~mA} \end{aligned}$ |  |  |  |  | 14.07 |  |  |  |  | V |
|  | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=15 \mathrm{~mA} \\ & V_{D D}=15 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=20 \mathrm{~mA} \end{aligned}$ | 13.6 |  |  | 13.6 | 13.95 |  | 13.2 |  |  | V |
|  | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{IOH}_{\mathrm{O}}=20 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=25 \mathrm{~mA} \end{aligned}$ |  |  |  |  | 13.8 |  |  |  |  | V |
| Low Level Output Current (IOL) | $V_{\text {DD }}=5 \mathrm{~V}, \mathrm{~V}_{\text {OL }}=0.4 \mathrm{~V}$ | 0.64 |  |  | 0.51 | 0.88 |  | 0.36 |  |  | mA |
|  | $\begin{aligned} & V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{OL}}=0.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{OL}}=1.5 \mathrm{~V} \end{aligned}$ | 1.6 |  |  | 1.3 | 2.25 |  | 0.9 |  |  | mA |
|  |  | 4.2 |  |  | 3.4 | 8.8 |  | 2.4 |  |  | mA |
| Input Current (IIN) | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V} \end{aligned}$ |  |  | -0.10 |  | $-10^{-5}$ | -0.10 |  |  | -1.0 | $\mu \mathrm{A}$ |
|  |  |  |  | 0.10 |  | $10^{-5}$ | 0.10 |  |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: Devices should not be connected with power on.

DC Electrical Characteristics cD4511BC


## AC Electrical Characteristics

$T_{A}=25^{\circ} \mathrm{C}$ and $C_{L}=50 \mathrm{pF}$, typical temperature coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$.

| PARAMETER | CONDITIONS | CD4511BX |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP | MAX |  |
| Input Capacitance ( $\mathrm{C}_{\text {IN }}$ ) | $\mathrm{V}_{\text {IN }}=0$ |  | 5.0 | 7.5 | pF |
| Output Rise Time (tr) (Figure 1a) | $V_{D D}=5 \mathrm{~V}$ |  | 40 | 80 | ns |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 30 | 60 | ns |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 25 | 50 | ns |
| Output Fall Time (tf) (Figure 1a) | $V_{D D}=5 \mathrm{~V}$ |  | 125 | 250 | ns |
|  | $V_{\text {DD }}=10 \mathrm{~V}$ |  | 75 | 150 | ns |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 65 | 130 | ns |
| Turn-Off Delay Time (Data) (tplH) (Figure 1a) | $V_{D D}=5 \mathrm{~V}$ |  | 640 | 1280 | ns |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 250 | 500 | ns |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 175 | 350 | ns |
| Turn-On Delay Time (Data) (tpHL) (Figure 1a) | $V_{\text {DD }}=5 \mathrm{~V}$ |  | 720 | 1440 | ns |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 290 | 580 | ns |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 195 | 400 | ns |
| Turn-Off Delay Time (Blank) (tPLH) (Figure 1a) | $V_{D D}=5 \mathrm{~V}$ |  | 320 | 640 | ns |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 130 | 260 | ns |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 100 | 200 | ns |
| Turn-On Delay Time (Blank) (tPHL) (Figure 1a) | $V_{D D}=5 \mathrm{~V}$ |  | 485 | 970 | ns |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 200 | 400 | ns |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 160 | 320 | ns |
| Turn-Off Delay Time (Lamp Test) (tpHL) (Figure 1a) | $V_{D D}=5 \mathrm{~V}$ |  | 313 | 625 | ns |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 125 | 250 | ns |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 90 | 180 |  |
| Turn-On Delay Time (Lamp Test) (tpHL) (Figure 1a) | $V_{D D}=5 \mathrm{~V}$ |  | 313 | 625 | ns |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 125 | 250 | ns |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 90 | 180 | ns |
| Setup Time (tSETUP) (Figure 1b) | $V_{D D}=5 \mathrm{~V}$ | 180 | 90 |  | ns |
|  | $V_{D D}=10 \mathrm{~V}$ | 76 | 38 |  | ns |
|  | $V_{D D}=15 \mathrm{~V}$ | 40 | 20 |  | ns |
| Hold Time (thold) (Figure 1b) | $V_{D D}=5 \mathrm{~V}$ | 0 | -90 |  | ns |
|  | $V_{D D}=10 \mathrm{~V}$ | 0 | -38 |  | ns |
|  | $V_{D D}=15 \mathrm{~V}$ | 0 | -20 |  | ns |
| Minimum Latch Enable Pulse Width (PWLE) (Figure 1c) | $V_{D D}=5 \mathrm{~V}$ | 520 | 260 |  | ns |
|  | $V_{D D}=10 \mathrm{~V}$ | 220 | 110 |  | ns |
|  | $V_{D D}=15 \mathrm{~V}$ | 130 | 65 |  | ns |

Switching Time Waveforms


FIGURE 1.

## Typical Applications

Light Emitting Diode (LED) Readout


## Gas Discharge Readout




Liquid Crystal (LC) Readout


Direct de drive of LC's not recommended for life of LC readouts.

Typical Applications (Contrd.)

## CD4512M／CD4512C 8－Channel Data Selector

## General Description

The CD4512M／CD4512C 8－channel data selector is a complementary MOS（CMOS）circuit constructed with N － and P－channel enhancement mode transistors．This data selector is primarily used as a digital signal multiplexer selecting 1 of 8 inputs and routing the signal to a TRI－ STATE ${ }^{\circledR}$ output．A high level at the Inhibit input forces a low level at the output．A high level at the Output Enable $(\overline{\mathrm{OE}})$ input forces the output into the TRI－STATE condition． Low levels at both the Inhibit and（ $\overline{\mathrm{OE}}$ ）inputs allow nor－ mal operation．
TRI－STATE is a trademark of National Semiconductor Corp．

Features
$\begin{array}{lr}\text {－Wide supply voltage range } & 3.0 \mathrm{~V}-15 \mathrm{~V} \\ \text {－High noise immunity } & 0.45 \mathrm{~V}_{\mathrm{DD}} \text {（typ．）}\end{array}$
－TRI－STATE output
－Low quiescent power dissipation $\begin{array}{r}0.25 \mu \mathrm{~W} / \text { package } \\ \text {（typ．）＠} \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}\end{array}$
■ Plug－in replacement for Motorola MC14512

## Connection Diagram and Truth Table

Dual－In－Line Package


| ADDRESS INPUTS |  |  | CONTROL <br> INPUTS |  | OUTPUT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| C | B | A | INHIBIT | $\overline{\text { OE }}$ | Z |
| 0 | 0 | 0 | 0 | 0 | X0 |
| 0 | 0 | 1 | 0 | 0 | X1 |
| 0 | 1 | 0 | 0 | 0 | X2 |
| 0 | 1 | 1 | 0 | 0 | X3 |
| 1 | 0 | 0 | 0 | 0 | X4 |
| 1 | 0 | 1 | 0 | 0 | X5 |
| 1 | 1 | 0 | 0 | 0 | X6 |
| 1 | 1 | 1 | 0 | 0 | X7 |
| $\emptyset$ | $\emptyset$ | $\emptyset$ | 1 | 0 | 0 |
| $\emptyset$ | $\emptyset$ | $\emptyset$ | $\emptyset$ | 1 | $\mathrm{Hi}-\mathrm{Z}$ |

$\emptyset=$ Don＇t care
$\mathrm{Hi}-\mathrm{Z}=$ TRI－STATE® condition
$X_{n}=$ Data at input $n$

## Absolute Maximum Ratings

（Notes 1 \＆2）
$V_{D D}$ Supply Voltage
$\mathrm{V}_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{S}}$ Storage Temperature Range
$P_{D}$ Package Dissipation
$\mathrm{T}_{\mathrm{L}}$ Lead Temperature（Soldering， 10 seconds）

Recommended Operating Conditions
（Note 2）


DC Electrical Characteristics CD4512M（Note 2）


DC Electrical Characteristics CD4512C（Note 2）

| Parameter | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min． | Max． | Min． | Typ． | Max． | Min． | Max． |  |
| IDD Quiescent Device Current | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  | 20 |  | 0.005 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.010 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 0.015 | 80 |  | 600 | $\mu \mathrm{A}$ |
| VoL Low Level Output Voltage | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| $V_{\mathrm{OH}}$ High Level Output Voltage | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | v |
|  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10.0 |  | 9.95 |  | v |
|  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15.0 |  | 14.95 |  | v |
| $V_{\text {IL }}$ Low Level Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | v |
|  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{0}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | $v$ |
|  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | v |
| $\mathrm{V}_{\mathrm{IH}}$ High Level Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=4.5 \mathrm{~V}$ | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  | $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.0 \mathrm{~V}$ | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | $v$ |
|  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |

DC Electrical Characteristics (cont'd) CD4512C (Note 2)

| Parameter | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IoL Low Level Output Current | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.4 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 0.23 \\ 0.60 \\ 1.8 \end{gathered}$ |  | $\begin{gathered} 0.20 \\ 0.50 \\ 1.5 \end{gathered}$ | $\begin{gathered} 0.78 \\ 2.0 \\ 7.8 \end{gathered}$ |  | $\begin{gathered} 0.16 \\ 0.09 \\ 1.2 \end{gathered}$ | , | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $\mathrm{I}_{\mathrm{OH}}$ High Level Output Current | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=2.5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{O}=113.5 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & -0.23 \\ & -0.23 \\ & -0.69 \end{aligned}$ |  | $\begin{aligned} & -0.20 \\ & -0.20 \\ & -0.60 \end{aligned}$ | $\begin{aligned} & -1.7 \\ & -0.9 \\ & -3.5 \end{aligned}$ |  | $\begin{aligned} & -0.16 \\ & -0.16 \\ & -0.48 \end{aligned}$ |  | mA <br> mA <br> $m A$ |
| IN Input Current | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} -0.3 \\ 0.3 \end{array}$ |  | $-10^{-5}$ $10^{-5}$ | -0.3 0.3 |  | -1.0 1.0 | $\mu \mathrm{A}$ $\mu \mathrm{A}$ |
| Ioz TRI-STATE ${ }^{\text {© }}$ Output Current | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0 \mathrm{~V}$ or 15 V |  | $\pm 1.0$ |  | $\pm 10^{-5}$ | $\pm 1.0$ |  | $\pm 7.5$ | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$

| Parameter |  | Conditions | CD4512M |  |  | CD4512C |  |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Typ. | Max. | Min. | Typ. | Max. |  |
| $\mathrm{t}_{\text {PHL }}$ | Propagation Delay High-to-Low Level |  | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 225 \\ 75 \\ 57 \end{gathered}$ | $\begin{aligned} & 500 \\ & 175 \\ & 130 \end{aligned}$ |  | $\begin{gathered} 225 \\ 75 \\ 57 \end{gathered}$ | $\begin{aligned} & 750 \\ & 200 \\ & 150 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {PLH }}$ | Propagation Delay Low-to-High Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 225 \\ 75 \\ 57 \end{gathered}$ | $\begin{aligned} & 500 \\ & 175 \\ & 130 \end{aligned}$ |  | $\begin{gathered} 225 \\ 75 \\ 57 \end{gathered}$ | $\begin{aligned} & 750 \\ & 200 \\ & 150 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{t}_{\text {THL }}, \mathrm{t}_{\text {TLH }}$ | Transition Time | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 70 35 25 | $\begin{gathered} 175 \\ 75 \\ 55 \end{gathered}$ |  | $\begin{aligned} & 70 \\ & 35 \\ & 25 \end{aligned}$ | 175 75 55 | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $t_{\text {PHz }}, t_{\text {PLZ }}$ | Propagation Delay into TRI-STATE from Logic Level | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \\ & 19 \end{aligned}$ | $\begin{aligned} & 125 \\ & 75 \\ & 60 \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \\ & 19 \end{aligned}$ | $\begin{aligned} & 125 \\ & 75 \\ & 60 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {PZH, }} \mathrm{t}_{\text {pzL }}$ | Propagation Delay to Logic Level from TRI-STATE | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \\ & 19 \end{aligned}$ | $\begin{aligned} & 125 \\ & 75 \\ & 60 \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \\ & 19 \end{aligned}$ | 125 75 60 | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | (Note 3) |  | 7.5 | 15 |  | 7.5 | 15 | pF |
| $\mathrm{C}_{\text {OUT }}$ | TRISTATE Output Capacitance | (Note 3) |  | 7.5 | 15 |  | 7.5 | 15 | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacity | (Note 4) |  | 150 |  |  | 150 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $V_{S S}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: Capacitance guaranteed by periodic testing.
Note 4: $C_{P D}$ determines the no load AC power of any CMOS device. For complete explanation, see 54C/74C Family Characteristics application note AN-90.

## Logic Diagram



## AC Test Circuit and Switching Time Waveforms




| TEST | INHIBIT | A | X0 |
| :---: | :--- | :--- | :--- |
| 1 | PG | GND | VDD |
| 2 | GND | PG | $V_{D D}$ |
| 3 | GND | GND | PG |

## TRI-STATE AC Test Circuit and Switching Time Waveforms



SWITCH POSITIONS FOR TRI-STATE TEST

| TEST | S1 | S2 | S3 | S4 |
| :--- | :--- | :--- | :--- | :--- |
| tPHZ | Open | Closed | Closed | Open |
| tPLZ | Closed | Open | Open | Closed |
| tPZL | Closed | Open | Open | Closed |
| tPZH | Open | Closed | Closed | Open |

## General Description

The CD4512BM/CD4512BC buffered 8-channel data selector is a complementary MOS (CMOS) circuit constructed with N - and P -channel enhancement mode transistors. This data selector is primarily used as a digital signal multiplexer selecting 1 of 8 inputs and routing the signal. to a TRI-STATE ${ }^{\oplus}$ output. A high level at the Inhibit input forces a low level at the output. A high level at the Output Enable ( $\overline{\mathrm{OE}}$ ) input forces the output into the TRI-STATE condition. Low levels at both the Inhibit and ( $\overline{\mathrm{OE}})$ inputs allow normal operation.

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## Connection Diagram and Truth Table

Dual-In-Line Package


| ADDRESS INPUTS |  |  | CONTROL <br> INPUTS |  | OUTPUT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| C | B | A | INHIBIT | $\overline{\text { OE }}$ | Z |
| 0 | 0 | 0 | 0 | 0 | X0 |
| 0 | 0 | 1 | 0 | 0 | $\times 1$ |
| 0 | 1 | 0 | 0 | 0 | X2 |
| 0 | 1 | 1 | 0 | 0 | X3 |
| 1 | 0 | 0 | 0 | 0 | X4 |
| 1 | 0 | 1 | 0 | 0 | X5 |
| 1 | 1 | 0 | 0 | 0 | X6 |
| 1 | 1 | 1 | 0 | 0 | X7 |
| $\emptyset$ | $\emptyset$ | $\emptyset$ | 1 | 0 | 0 |
| $\emptyset$ | $\emptyset$ | $\emptyset$ | $\emptyset$ | 1 | $\mathrm{Hi}-\mathrm{Z}$ |

[^24]
## Absolute Maximum Ratings

(Notes 1 \& 2)
$V_{D D}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{S}}$ Storage Temperature Range
PD Package Dissipation
TL Lead Temperature (Soldering, 10 seconds)
-0.5 to $+18 V_{D C}$
-0.5 to $V_{D D}+0.5 V_{D C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$300^{\circ} \mathrm{C}$

Recommended Operating Conditions
(Note 2)

| $V_{D D} D C$ Supply Voltage | 3.0 to $15 V_{D C}$ |
| :--- | ---: |
| $V_{\text {II }}$ Input Voltage | 0 to $V_{D D} V_{D C}$ |
| $T_{A}$ Operating Temperature Range |  |
| CD4512BM | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD4512BC | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

DC Electrical Characteristics CD4512BM (Note 2)

| Parameter |  | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IDD | Quiescent |  | $V_{D D}=5.0 \mathrm{~V}$ |  | 5.0 |  | 0.005 | 5.0 |  | 150 | $\mu \mathrm{A}$ |
|  | Device Current | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  | 0.010 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  | 0.015 | 20 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {OL }}$ | Low Level | $V_{D D}=5.0 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | Output Voltage | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level | $V_{D D}=5.0 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  | Output Voltage | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10.0 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15.0 |  | 14.95 |  | V |
| VIL | Low Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  | Input Voltage | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{1 H}$ | High Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=4.5 \mathrm{~V}$ | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  | Input Voltage | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.0 \mathrm{~V}$ | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=13.5 \mathrm{~V}$ | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| Iol | Low Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.78 |  | 0.36 |  | mA |
|  | Output Current | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.0 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 7.8 |  | 2.4 |  | mA |
| $\mathrm{IOH}^{\text {O }}$ | High Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -1.7 |  | -0.36 |  | mA |
|  | Output Current | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -1.9 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -3.5 |  | -2.4 |  | mA |
|  | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1 N}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |
| Ioz | TRI-STATE ${ }^{\text {® }}$ | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=0 \mathrm{~V}$ |  | $\pm 0.1$ |  | $-10^{-5}$ | $\pm 0.1$ |  | $\pm 3.0$ | $\mu \mathrm{A}$ |
|  | Output Current | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=15 \mathrm{~V}$ |  |  |  | $10^{-5}$ |  |  |  | $\mu \mathrm{A}$ |

DC Electrical Characteristics CD4512BC (Note 2)

| Parameter | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IDD Quiescent | $V_{D D}=5.0 \mathrm{~V}$ |  | 20 |  | 0.005 | 20 |  | 150 | $\mu \mathrm{A}$ |
| Device Current | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.010 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 0.015 | 80 |  | 600 | $\mu \mathrm{A}$ |
| V OL Low Level | $V_{D D}=5.0 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| Output Voltage | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ High Level | $V_{D D}=5.0 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
| Output Voltage | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10.0 |  | 9.95 |  | V |
|  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15.0 |  | 14.95 |  | V |
| VIL Low Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
| Input Voltage | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | V |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $V_{I H}$ High Level | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.5 \mathrm{~V}$ | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
| Input Voltage | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.0 \mathrm{~V}$ | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | V |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |

DC Electrical Characteristics (cont'd) CD4512BC (Note 2)

| Parameter | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IOL Low Level Output Current | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=0.4 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 0.52 \\ 1.3 \\ 3.6 \end{gathered}$ |  | $\begin{gathered} 0.44 \\ 1.1 \\ 3.4 \end{gathered}$ | $\begin{gathered} \hline 0.78 \\ 2.0 \\ 7.8 \end{gathered}$ |  | $\begin{gathered} 0.36 \\ 0.9 \\ 2.4 \end{gathered}$ |  | mA <br> mA <br> mA |
| $\mathrm{IOH}_{\mathrm{OH}}$ High Level Output Current | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=2.5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{O}=113.5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} -0.52 \\ -1.3 \\ -3.6 \end{gathered}$ |  | $\begin{aligned} & -0.44 \\ & -1.1 \\ & -3.4 \end{aligned}$ | $\begin{aligned} & -1.7 \\ & -0.9 \\ & -3.5 \end{aligned}$ |  | $\begin{aligned} & -0.36 \\ & -0.9 \\ & -2.4 \end{aligned}$ |  | mA <br> mA <br> mA |
| $\mathrm{I}_{\mathrm{N}}$ Input Current | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V} \end{aligned}$ |  | -0.3 0.3 |  | $\begin{array}{r} -10^{-5} \\ 10^{-5} \end{array}$ | -0.3 0.3 |  | $\begin{array}{r} -1.0 \\ 1.0 \end{array}$ | $\mu \mathrm{A}$ $\mu \mathrm{A}$ |
| Ioz TRI-STATE ${ }^{\oplus}$ Output Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0 \mathrm{~V}$ or 15 V |  | $\pm 1.0$ |  | $\pm 10^{-5}$ | $\pm 1.0$ |  | $\pm 7.5$ | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{t}}=20 \mathrm{~ns}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$

| Parameter |  | Conditions | CD4512BM |  |  | CD4512BC |  |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Typ. | Max. | Min. | Typ. | Max. |  |
| $t_{\text {PHL }}$ | Propagation Delay High-to-Low Level |  | $V_{D D}=5.0 \mathrm{~V}$ |  | 225 | 500 |  | 225 | 750 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 75 | 175 |  | 75 | 200 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 57 | 130 |  | 57 | 150 | ns |
| $t_{\text {PLH }}$ | Propagation Delay Low-to-High Level | $V_{D D}=5.0 \mathrm{~V}$ |  | 225 | 500 |  | 225 | 750 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 75 | 175 |  | 75 | 200 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 57 | 130 |  | 57 | 150 | ns |
| $t_{\text {THL }}, \mathrm{t}_{\text {TLH }}$ | Transition Time | $V_{D D}=5.0 \mathrm{~V}$ |  | 70 | 175 |  | 70 | 175 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 35 | 75 |  | 35 | 75 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 25 | 55 |  | 25 | 55 | ns |
| $t_{\text {PHZ }}, t_{\text {PLZ }}$ | Propagation Delay into TRI-STATE from Logic Level | $V_{D D}=5.0 \mathrm{~V}$ |  | 50 | 125 |  | 50 | 125 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 25 | 75 |  | 25 | 75 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 19 | 60 |  | 19 | 60 | ns |
| $\mathrm{t}_{\text {PZH }}, \mathrm{t}_{\text {PZL }}$ | Propagation Delay to Logic Level from TRI-STATE | $V_{D D}=5.0 \mathrm{~V}$ |  | 50 | 125 |  | 50 | 125 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 25 | 75 |  | 25 | 75 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 19 | 60 |  | 19 | 60 | ns |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance | (Note 3) |  | 7.5 | 15 |  | 7.5 | 15 | pF |
| Cout | TRI-STATE Output Capacitance | (Note 3) |  | 7.5 | 15 |  | 7.5 | 15 | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacity | (Note 4) |  | 150 |  |  | 150 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: Capacitance guaranteed by periodic testing.
Note 4: $C_{P D}$ determines the no load AC power of any CMOS device. For complete explanation, see 54CI74C Family Characteristics application note AN-90.

Logic Diagram


Typical Application

Serial Data Routing Interface



SWITCH POSITIONS FOR TRI－STATE TEST

| TEST | S1 | S2 | S3 | S4 |
| :--- | :--- | :--- | :--- | :--- |
| tPHZ | Open | Closed | Closed | Open |
| tPLZ | Closed | Open | Open | Closed |
| tPZL | Closed | Open | Open | Closed |
| tPZH | Open | Closed | Closed | Open |

## CD4514BM/CD4514BC, CD4515BM/CD4515BC 4-Bit Latched/4-to-16 Line Decoders

## General Description

The CD4514B and CD4515B are 4-to-16 line decoders with latched inputs implemented with complementary MOS (CMOS) circuits constructed with N - and P-channel enhancement mode transistors. These circuits are primarily used in decoding applications where low power dissipation and/or high noise immunity is required.

The CD4514B (output active high option) presents a logical " 1 " at the selected output, whereas the CD4515B presents a logical " 0 " at the selected output. The input latches are R-S type flip-flops, which hold the last input data presented prior to the strobe transition from " 1 " to " 0 ". This input data is decoded and the corresponding output is activated. An output inhibit line is also available.

Features

| - Wide supply voltage range | 3.0 V to 15 V |
| :---: | :---: |
| - High noise immunity | 0.45 V DD (typ.) |
| - Low power TTL compatibility | fan out of 2 driving 74L |
| - Low quiescent power dissipation | $0.025 \mu \mathrm{~W} /$ package (typ.) @ $5.0 \mathrm{~V}_{\mathrm{DC}}$ |
| - Single supply operation |  |
| - Input impedance $=10^{12} \Omega$ typically |  |
| Plug-in replacement for MC14514, | MC14515 |

Logic and Connection Diagrams


## Absolute Maximum Ratings

(Notes 1 and 2)
$V_{D D}$ DC Supply Voltage
-0.5 V to +18 V
$V_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
PD Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
-0.5 V to $\mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW
$300^{\circ} \mathrm{C}$

Recommended Operating Conditions
(Note 2)
$V_{D D} D C$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range

> CD4514BM, CD4515BM

CD4514BC, CD4515BC
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

DC Electrical Characteristics CD4514BM, CD4515BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $5.0$ |  | 0.005 | 5.0 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $10.0$ |  |  |  | 0.010 | 10.0 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $20.0$ |  |  |  | 0.015 | 20.0 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\begin{aligned} & V_{I H}=V_{D D} \cdot \\| O \mid<1 \mu \mathrm{~A} \\ & V_{D D}=5 \mathrm{~V}, V_{I L}=0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  |  |  |  |  |  |  |  |
|  |  |  | 0.05 |  |  | 0 | 0.05 |  | 0.05 | $V$, |
|  |  |  | 0.05 |  |  | 0 | 0.05 |  | 0.05 | V |
|  |  |  | 0.05 |  |  | 0 | 0.05 |  | 0.05 | V |
| VOH | High Level Output Voltage | $V_{\text {IH }}=V_{\text {DD }}, \\|_{\text {O }} \mid<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {DD }}=5 \mathrm{~V}, \mathrm{~V}_{\text {IL }}=0 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10.0 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15.0 |  | 14.95 | - | V |
| VIL | Low Level Input Voltage | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  |  |  |  |  | , |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \\|_{\mathrm{O}}<1 \mu \mathrm{~A}$ |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| VIH | High Level Input Voltage | $V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \\|_{\mathrm{O}} \mid<1 \mu \mathrm{~A}$ | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | $V$ |
| IOL | Low Level Output Current | $V_{\text {DD }}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.80 |  | 2.40 |  | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.64 |  | $-0.51$ | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.80 |  | -2.40 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

DC Electrical Characteristics CD4514BC, CD4515BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | 204080 |  | $\begin{array}{\|l\|} \hline 0.005 \\ 0.010 \\ 0.015 \end{array}$ |  | $\begin{aligned} & 20 \\ & 40 \\ & 80 \end{aligned}$ | $\begin{aligned} & 150 \\ & 300 \\ & 600 \end{aligned}$ |  | $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ |
|  |  |  |  |  |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |  |  |  |  |  |
| VOL | Low Level Output Voltage | $\begin{aligned} & V_{I L}=0 V ; V_{I H}=V_{D D} . \\ & \\|O\\|<1 \mu A \end{aligned}$ |  |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$$V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |  |
|  |  |  |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |  |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |  |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\begin{aligned} & V_{I L}=0 \mathrm{~V}, V_{I H}=V_{D D} . \\ & \\| O I<1 \mu \mathrm{~A} \\ & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |  |  |  |  |
|  |  |  | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | v |  |
|  |  |  | 9.95 |  | 9.95 | 10.0 |  | 9.95 |  | v |  |
|  |  |  | 14.95 |  | 14.95 | 15.0 |  | 14.95 |  | V |  |

DC Electrical Characteristics (Continued) CD4514BC, CD4515BC (Note 2)

|  | PARAMETER | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| VIL | Low Level Input Voltage | $\\| \mathrm{l} \mathrm{I}^{\prime}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | V |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{1} \mathrm{H}$ | High Level Input Voltage | $\\|_{\mathrm{O}}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{O}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V}$ | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | V |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{O}=0.4 \mathrm{~V}$ | 0.52 | - | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| 1 OH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.90 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -3.6 |  | $-3.0$ | -8.8 |  | -2.4 |  | $m A$ |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | '-0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics All types $C_{L}=50 \mathrm{pF}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$ unless otherwise specified

| Parameter |  | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ${ }^{\text {tTHL, tTLH }}$ | Transition Times | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| tPLH, tPHL | Propagation Delay Times | $V_{D D}=5 \mathrm{~V}$ |  | 550 | 1100 | ns |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}$ |  | 225 | 450 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 150 | 300 | ns |
| tPLH, tPHL | Inhibit Propagation Delay | $V_{D D}=5 \mathrm{~V}$ |  | 400 | 800 | ns |
|  | Times | $V_{D D}=10 \mathrm{~V}$ |  | 150 | 300 | ns |
|  |  | - $\mathrm{V}_{D D}=15 \mathrm{~V}$ |  | 100 | 200 | ns |
| tsu | Set Up Time | $V_{\text {D }}=5 \mathrm{~V}$ |  | 125 | 250 | ns |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 38 | 75 | ns |
| ${ }^{\text {tw }} \mathrm{H}$ | Strobe Pulse Width | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 175 | 350 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 38 | 75 | ns |
| ${ }_{\text {CPD }}$ | Power Dissipation Capacitance | Per Package, (Note 4) |  | 150 |  | pF |
| CIN | Input Capacitance | Any Input, (Note 3) |  | 5 | 7.5 | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and 'Electrical Characteristics' provide conditions for actual device operation.
Note 2: $V_{S S}=0 V$ unless otherwise specified.
Note 3. Capacitance is guaranteed by periodic testing.
Note 4: CPD determines the no load AC power consumption of any CMOS device. For complete explanation, see 54C\&74C Family Characteristics application note, AN-90.

## Truth Table

DECODE TRUTH TABLE (Strobe $=1$ )

| INHIBIT | DATA INPUTS |  |  |  | SELECTED OUTPUT$\begin{aligned} & \text { CD4514 }=\text { LOGIC " } 1 \text { " } \\ & \text { CD4515 }=\text { LOGIC " } 0 \text { " } \end{aligned}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | D | C | B | A |  |
| 0 | 0 | 0 | 0 | 0 | So |
| 0 | 0 | 0 | 0 | 1 | S1 |
| 0 | 0 | 0 | 1 | 0 | S2 |
| 0 | 0 | 0 | 1 | 1 | S3 |
| 0 | 0 | 1 | 0 | 0 | S4 |
| 0 | 0 | 1 | 0 | 1 | S5 |
| 0 | 0 | 1 | 1 | 0 | S6 |
| 0 | 0 | 1 | 1 | 1 | S7 |
| 0 | 1 | 0 | 0 | 0 | S8 |
| 0 | 1 | 0 | 0 | 1 | S9 |
| 0 | 1 | 0 | 1 | 0 | S10 |
| 0 | 1 | 0 | 1 | 1 | S11 |
| 0 | 1 | 1 | 0 | 0 | S12 |
| 0 | 1 | 1 | 0 | 1 | S13 |
| 0 | 1 | 1 | 1 | 0 | S14 |
| 0 | 1 | 1 | 1 | 1 | S15 |
| 1 | X | X | X | X | All Outputs $=0$, CD4514 <br> All Outputs $=1, \operatorname{CD} 4515$ |

$X=$ Don't care

## AC Test Circuit and Switching Time Waveforms



FIGURE 1

## Applications

Two CD4512 8-channel data selectors are used here with the CD4514B 4-bit latch/decoder to effect a complex data routing system. A total of 16 inputs from data registers are selected and transferred via a TRI-STATE ${ }^{\circledR}$ data bus to a data distributor for rearrangement and entry into 16 output registers. In this way sequential data can be re-routed or intermixed according to patterns determined by data select and distribution inputs.

Data is placed into the routing scheme via the 8 inputs on both CD4512 data selectors. One register is assigned to each input. The signals on A0, A1 and A2 choose 1 -of-8 inputs for transfer out to the TRI-STATE data bus. A fourth signal, labelled Dis, disables one of the CD4512 selectors, assuring transfer of data from only one register.

In addition to a choice of input registers, 1-16, the rate of transfer of the sequential information can also be varied. That is, if the CD4512 were addressed at a rate
that is 8 times faster than the shift frequency of the input registers, the most significant bit (MSB) from each register could be selected for transfer to the data bus. Therefore, all of the most significant bits from all of the registers can be transferred to the data bus before the next most significant bit is presented for transfer by the input registers.

Information from the TRI-STATE bus is redistributed by the CD4514B 4-bit latch/decoder. Using the 4 -bit address, INA-IND, the information on the inhibit line can be transferred to the addressed output line to the desired output registers, A-P. This distribution of data bits to the output registers can be made in many complex patterns. For example, all of the most significant bits from the input registers can be routed into output register $A$, all of the next most significant bits into register $B$, etc. In this way horizontal, vertical, or other methods of data slicing can be implemented.


## CD4518BM/CD4518BC, CD4520BM/CD4520BC Dual Synchronous Up Counters

## General Description

The CD4518BM/CD4518BC dual BCD counter and the CD4520BM/CD4520BC dual binary counter are implemented with complementary MOS (CMOS) circuits constructed with N - and P-channel enhancement mode transistors.

Each counter consists of two identical, independent, synchronous, 4 -stage counters. The counter stages are toggle flip-flops which increment on either the positiveedge of CLOCK or negative-edge of ENABLE, simplifying cascading of multiple stages. Each counter can be asynchronously cleared by a high level on the RESET
line, All inputs are protected against static discharge by diode clamps to both $V_{D D}$ and $V_{S S}$.

## Features

- Wide supply voltage range 3.0 V to 15 V
- High noise immunity
$0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
- Low power TTL compatibility
fan out of 2 driving 74L or 1 driving 74LS
a 6 MHz counting rate (typ.) at $V_{D D}=10 \mathrm{~V}$

| CLOCK | ENABLE | RESET | ACTION |
| :---: | :---: | :---: | :---: |
| $\Gamma$ | 1 | 0 | Increment counter |
| 0 | $\checkmark$ | 0 | Increment counter |
| L | $x$ | 0 | No change |
| X | J | 0 | No change |
| 」 | 0 | 0 | No change |
| 1 |  | 0 | No change |
| $\times$ | X | 1 | Q1 thru Q4 $=0$ |

$X=$ Don't Care
Connection Diagram


Absolute Maximum Ratings
(Notes 1 and 2)
$V_{D D}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
$T_{S}$ Storage Temperature Range
$P_{D}$ Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
-0.5 V to +18 V
-0.5 V to $\mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW $300^{\circ} \mathrm{C}$

Recommended Operating Conditions
(Note 2)
$V_{D D}$ Supply Voltage
$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{A}}$ Operating Temperature Range CD4518BM, CD4520BM
CD4518BC, CD4520BC

3 V to 15 V OV to $V_{D D}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## DC Electrical Characteristics CD4518BM/CD4520BM (Note 2)



## DC Electrical Characteristics cD4518BC/CD4520BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 20 |  | 0.01 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.01 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 0.01 | 80 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\\| \mathrm{O} \mid<1 \mu \mathrm{~A}, \mathrm{~V}_{1 H}=V_{\text {DD }}, V_{I L}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $\mid{ }^{\text {O }}$ I $<1 \mu \mathrm{~A}, \mathrm{~V}_{1 H}=\mathrm{V}_{\text {DD }}^{\prime}, V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |

DC Electrical Characteristics (Cont'd.) CD4518BC/CD4520BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40 \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\prime \prime} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| VIL | Low Level Input Voltage |  | $\|1 \mathrm{O}\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {DD }}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| VIH | High Level Input Voltage | $\\| \mathrm{l} \mathrm{l}^{\prime}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| 1 OL | Low Level Output Current | $V_{\text {IH }}=V_{\text {DD }}, V_{\text {IL }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | $m \mathrm{~A}$ |
| ${ }^{1} \mathrm{OH}$ | High Level Output Current | $V_{I H}=V_{D D}, V_{I L}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | $-2.25$ |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{\text {DD }}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k} \Omega, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL, tPLH | Propagation Delay Time, Clock $\rightarrow$ Q | $V_{D D}=5 \mathrm{~V}$ |  | 325 | 650 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | . | 110 | 225 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 85 | 170 | ns |
| tPHL | Propagation Delay Time Reset $\rightarrow 0$ | $V_{D D}=5 \mathrm{~V}$ |  | 220 | 560 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 90 | 230 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 65 | 160 | ns |
| ${ }^{\text {tTHL, }}$ tTLH | Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | 'ns |
| ${ }_{f} \mathrm{CL}$ | Maximum Clock Input Frequency | $V_{D D}=5 \mathrm{~V}$ | 1.5 | 3 |  | MHz |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 3.0 | 6 |  | MHz |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 4.0 | 8 |  | MHz |
| ${ }^{\text {tWL, }}$ 'WH | Minimum Clock Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 35 | 70 | ns |
| ${ }^{\text {treL }}$, $\mathrm{t}_{\text {F }}$ | Maximum Clock or Enable Rise and Fall Time | $V_{D D}=5 \mathrm{~V}$ | 15 |  |  | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 10 |  |  | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 5 |  |  | $\mu \mathrm{s}$ |
| tWH, twL | Minimum Enable Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 125 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 55 | 110 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| ${ }^{\text {tW }} \mathrm{H}$ | Minimum Reset Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 180 | 375 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 80 | 160 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 65 | 130 | ns |
| $C_{\text {IN }}$ | Input Capacitance | Any Input |  | 5 | 7.5 | pF |
| CPD | Power Dissipation Capacity | Either Counter, (Note 3) |  | 50 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $V_{S S}=0 V$ unless otherwise specified.
Note 3: CPD determines the no load ac power consumption of a CMOS device. For a complete explanation, see "54C/74C Family Characteristics," application note AN-90.

Decade Counter (CD4518B) 1/2 Device Shown


Binary Counter (CD4520B) 1/2 Device Shown


## Timing Diagrams



## Switching Time Waveforms



## CD4519BM/CD4519BC 4-Bit AND/OR Selector

## General Description

The CD4519B is a monolithic complementary MOS (CMOS) integrated circuit constructed with N - and P . channel enhancement mode transistors. Depending on the condition of the control inputs, this part provides three functions in one package: a 4-bit AND/OR selector, a quad 2-channel Data Selector, or a Quad Exclusive-NOR Gate. The device outputs have equal source and sink current capabilities and conform to the standard B series output drive and supply voltage ratings.

Features

- Wide supply voltage range 3.0 V to 15 V
- High noise immunity 0.45 VDD (typ.)
- Low power TTL compatibility
fan out of 2 driving 74L
or 1 driving 74LS
- $5 \mathrm{~V}-10 \mathrm{~V}-15 \mathrm{~V}$ parametric ratings
- Symmetrical output characteristics
- Maximum input leakage $1 \mu \mathrm{~A}$ at 15 V over full temperature range
- Second source of Motorola MC14519


## Logic Diagram



Connection Diagram


Truth Table

| CONTROL INPUTS |  | OUTPUT <br> $Z_{n}$ |  |
| :--- | :--- | :--- | :---: |
| $\mathbf{A}$ | $B$ | 0 |  |
| 0 | 0 | 0 |  |
| 0 | 1 | $Y_{n}$ |  |
| 1 | 0 | $X_{n}$ |  |
| 1 | 1 | $X_{n} \odot Y_{n}$ |  |

Note: $x_{1} \bigcirc r_{n}=\overline{x_{n} \bigodot} \bar{y}_{n}=x_{n} y_{n}+\bar{x}_{n} \bar{Y}_{n}$

Absolute Maximum Ratings
(Notes 1 and 2)
$V_{D D}$ dc Supply Voltage
$V_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
$P_{D}$ Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
(Note 2)
$V_{D D}$ de Supply Voltage
3 to $15 V_{D C}$ 0 to $V_{D D} V_{D C}$
$T_{A}$ Operating Temperature Range CD4519BM
CD4519BC
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

DC Electrical Characteristics CD45198M (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| ${ }^{\prime} \mathrm{DD}$ | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 1 |  | 0.005 | 1 |  | 30 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 2 |  | 0.006 | 2 |  | 60 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 4 |  | 0.007 | 4 |  | 120 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\mathrm{l}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $\|1 \mathrm{O}\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  |  | 15 |  | 14.95 |  | v |
| $V_{\text {IL }}$ | Low Level Input Voltage | $\mathrm{IIO}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2 | 1.5 |  | 1.5 | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V} \text { or } 9 \mathrm{~V}$ |  | 3.0 |  | 4 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | $v$ |
| $\mathrm{V}_{1} \mathrm{H}$ | High Level Input Voltage | $11 \mathrm{O}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 3 |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 6 |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 9 |  | 11.0 |  | $v$ |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| IN | Input Current |  |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

## DC Electrical Characteristics cD4519BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 4 |  |  | 4 |  | 30 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 8 |  |  | 8 |  | 60 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 16 |  |  | 16 |  | 120 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $\mid \mathrm{I}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $\mathrm{l}_{\mathrm{O}} \mathrm{l}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |

DC Electrical Characteristics (Cont'd.) CD4519BC (Note 2)

|  | PARAMETER | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| VIL | Low Level Input Voltage | $1101<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2 | 1.5 |  | 1.5 | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  | 4 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6 | 4.0 |  | 4.0 | v |
| $\mathrm{V}_{1 \mathrm{H}}$ | High Level Input Voltage | $1 \mathrm{O} \mathrm{O}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 3 |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 | 6 |  | 7.0 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 9 |  | 11.0 |  | v |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| IN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k} \Omega, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPHL, tPLH | Propagation Delay High-to-Low Level or Low-to-High Level | (Figure 1) |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 180 | 360 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 75 | 150 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 60 | 120 | ns |
| tTHL, tTLH | Transition Time | (Figure 1) |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 90 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| $\mathrm{CIN}_{1}$ | Average Input Capacitance | Any Input (Note 3) |  | 5 | 7.5 | pF |
| $\mathrm{C}_{\mathrm{pd}}$ | Power Dissipation Capacity | Any Gate (Note 4) |  | 25 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: Capacitance is guaranteed by periodic testing.
Note 4: $\mathrm{C}_{\text {pd }}$ determines the no load ac power consumption of any CMOS device. For complete explanation, see 54C/74C Family characteristics application note AN-90.

## AC Test Circuit and Switching Time Waveforms



FIGURE 1

## Typical Application



# CD4522BM/CD4522BC Programmable Divide-By-N 4-Bit BCD Counter <br> <br> CD4526BM/CD4526BC Programmable Divide-By-N <br> <br> CD4526BM/CD4526BC Programmable Divide-By-N 4-Bit Binary Counter 

 4-Bit Binary Counter}

## General Description

The CD4522BM/CD4522BC, CD4526BM/CD4526BC are CMOS programmable cascadable down counters with a decoded " 0 " state output for divide-by- $N$ applications. In single stage applications, the " 0 " output is applied to the Preset Enable input. For multi-stage applications, the " 0 " output is used in conjunction with the CF (Cascade Feedback) input to perform the divide-by-N function. The " 0 " output is normally at logical " 0 " level; it will go to a logical " 1 " state only when the counter is at its terminal count (0000) and if CF is at logical " 1 " level. Thus, CF acts as an active low inhibit for the " 0 " output. This feature allows cascade divide-by-N operations with no additional gate required (see Applications section). The Master Reset function provides synchronous initiation of divide-by-N cycles. The Clock Inhibit input allows disabling of the pulse counting function.

All inputs are protected against static discharge by diode clamps to $V_{D D}$ and $V_{S S}$.

## Features

- Wide supply voltage range
3.0 V to 18 V
- High noise immunity
- Low power TTL $0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.) compatibility
fan out of 2 driving 74L or 1 driving 74LS
- Quiescent current $=5 \mathrm{nA} /$ package (typ.) @ $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$
- Internally synchronous for high internal and external speed
- Logic edge-clocked design-incremented on positive transition of Clock or negative transition of Clock Inhibit
Medium speed $\quad 7.7 \mathrm{MHz}$ (typ.) @ $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$
- Asynchronous Preset Enable


## Applications

- Programmable down counter
- Programmable frequency divider
- Frequency synthesizers
- Phase-locked loops


## Connection Diagram



TOP VIEW

Absolute Maximum Ratings
(Notes 1 and 2)
VDD DC Supply Voltage
$V_{\text {IN }}$ Input Voltage
TS Storage Temperature Range
$P_{D}$ Package Dissipation
$\mathrm{T}_{\mathrm{L}}$ Lead Temperature (Soldering, 10 seconds)
-0.5 to $+18 \mathrm{VDC}_{\mathrm{DC}}$
-0.5 to $V_{D D}+0.5 V_{D C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
$300^{\circ} \mathrm{C}$
(Note 2)

| $V_{D D}$ DC Supply Voltage | 3 to $15 V_{D C}$ |
| :--- | ---: |
| $V_{\text {IN }}$ Input Voltage | 0 to $V_{D D} V_{D C}$ |
| $T_{A}$ Operating Temperature Range |  |
| CD4522BM, CD4526BM | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD4522BC, CD4526BC | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

DC Electrical Characteristics CD4522BM, CD4526BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 V \\ & V_{D D}=10 V \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 5 |  | 0.005 | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  |  |  | 10 |  | 0.010 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  |  |  | 20 |  | 0.015 | 20 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\\| \mathrm{O} \mid<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| VOH | High Level Output Voltage | $\left\|\mathrm{l}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  |  | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | V |
| V/H | High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{O}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 |  |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | $V$ |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

DC Electrical Characteristics CD4522BC, CD4526BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 20 |  | 0.005 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  |  |  | 40 |  | 0.010 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  |  |  | 80 |  | 0.015 | 80 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $\|10\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $\mathrm{ilO}_{\mathrm{O}}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| $V_{\text {IL }}$ | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  |  | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | v |

DC Electrical Characteristics (Continued) CD4522BC, CD4526BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| $V_{1 H}$ | High Level Input Voltage |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | V |
|  |  | $\mathrm{V}_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 |  |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | $v$ |
| 1 OL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 | -0.88 |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 | -2.25 |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| IN | Input Current | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tTHL or tTLH | Output Transition Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| tPHL \& tPLH | Propagation Delay Time From Clock to | $V_{D D}=5 \mathrm{~V}$ |  | 350 | 825 | ns |
|  | Q Outputs | $V_{D D}=10 \mathrm{~V}$ |  | 130 | 345 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 90 | 240 | ns |
| tPHL \& tPLH | Propagation Delay Time From Clock to | $V_{D D}=5 \mathrm{~V}$ |  | 200 | 500 | ns |
|  | "0' Output | $V_{D D}=10 \mathrm{~V}$ |  | 80 | 250 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ | : | 60 | 190 | ns |
| ${ }^{\text {PWC }}$ | Minimum Clock Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 120 | 280 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 120 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 35 | 85 | ns |
| ${ }^{\text {f CL }}$ | Maximum Clock Pulse Frequency | $V_{D D}=5 \mathrm{~V}$ |  | 2.9 |  | MHz |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 3.0 | 7.7 |  | MHz |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 4.0 | 11 |  | MHz |
| $\mathrm{trCL}^{\text {\& }} \mathrm{tfCL}$ | Maximum Clock or Inhibit Rise and Fall Time | $V_{D D}=5 \mathrm{~V}$ | 15 |  |  | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 15 |  |  | $\mu \mathrm{s}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 15 |  |  | $\mu \mathrm{s}$ |
| thold | Hold Time | $V_{D D}=5 \mathrm{~V}$ |  | 40 | 125 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 25 | 50 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20. | 40 | ns |
| PWPE | Minimum Preset Enable Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 120 | 280 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ | . | 50 | 120 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 35 | 85 | ns |
| PWMR | Minimum Master Reset Pulse Width | $V_{D D}=5 \mathrm{~V}$ |  | 160 | 350 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 75 | 180 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 50 | 120 | ns |
| CIN | Input Capacitance | (Note 3) |  | 5 | 7.5 | pF |
| CPD | Power Dissipation Capacitance | Per Package (Note 4) |  | 100 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specifíied.
Note 3: Capacitance is guaranteed by periodic testing.
Note 4: CPD determines the no load AC power consumption of any CMOS device. For complete explanation, see 54C/74C Family Characteristics application note, AN-90.

Logic Diagrams


Truth Tables and Count Sequences
Both Types

| CLOCK | INHIBIT | PRESET <br> ENABLE | MASTER <br> RESET | ACTION |
| :--- | :---: | :---: | :---: | :--- |
| 0 | 0 | 0 | 0 | No count |
| $\Gamma$ | 0 | 0 | 0 | Count 1 |
| X | 1 | 0 | 0 | No count |
| 1 | L | 0 | 0 | Count 1 |
| X | X | 1 | 0 | Preset |
| X | X | X | 1 | Reset |

CD4522BM/CD4522BC

| COUNT | OUTPUT |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Q4 | Q3 | Q2 | Q1 |
| 9 | 1 | 0 | 0 | 1 |
| 8 | 1 | 0 | 0 | 0 |
| 7 | 0 | 1 | 1 | 1 |
| 6 | 0 | 1 | 1 | 0 |
| 5 | 0 | 1 | 0 | 1 |
| 4 | 0 | 1 | 0 | 0 |
| 3 | 0 | 0 | 1 | 1 |
| 2 | 0 | 0 | 1 | 0 |
| 1 | 0 | 0 | 0 | 1 |
| 0 | 0 | 0 | 0 | 0 |



CD4526BM/CD4526BC

| COUNT | OUTPUT |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Q4 | Q3 | Q2 | $\mathbf{Q 1}$ |
| 15 | 1 | 1 | 1 | 1 |
| 14 | 1 | 1 | 1 | 0 |
| 13 | 1 | 1 | 0 | 1 |
| 12 | 1 | 1 | 0 | 0 |
| 11 | 1 | 0 | 1 | 1 |
| 10 | 1 | 0 | 1 | 0 |
| 9 | 1 | 0 | 0 | 1 |
| 8 | 1 | 0 | 0 | 0 |
| 7 | 0 | 1 | 1 | 1 |
| 6 | 0 | 1 | 1 | 0 |
| 5 | 0 | 1 | 0 | 1 |
| 4 | 0 | 1 | 0 | 0 |
| 3 | 0 | 0 | 1 | 1 |
| 2 | 0 | 0 | 1 | 0 |
| 1 | 0 | 0 | 0 | 1 |
| 0 | 0 | 0 | 0 | 0 |



Switching Time Waveforms

Test No. 1


Test No. 2


Test No. 3


Test No. 4


Tests No. 5 and 7


Test No. 6


## AC Test Circuits



FIGURE 1. Test Circuit

## Test Conditions

TABLE 1

| CHARACTERISTIC | TEST NO. | CLOCK | INHIBIT | PE | MR | DP ${ }_{n}$ | CF | OUTPUT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{tr}_{\mathrm{r}}, \mathrm{tf}^{\text {, }} \mathrm{tPLH}, \mathrm{tPHL}$ | 1 | PG1 | $\mathrm{V}_{\text {SS }}$ | $\mathrm{V}_{\text {SS }}$ | $V_{\text {SS }}$ | $\mathrm{V}_{\text {SS }}$ | $\mathrm{V}_{\text {SS }}$ | Q1 |
|  | 2 | $V_{\text {DD }}$ | PG1 | $V_{S S}$ | $V_{\text {SS }}$ | $V_{\text {SS }}$ | $V_{\text {SS }}$ | Q1 |
|  | 3 | $v_{\text {SS }}$ | $\mathrm{V}_{\text {SS }}$ | PG1 | $V_{S S}$ | PG2 | $V_{\text {SS }}$ | $\mathrm{a}_{\mathrm{n}}$ |
|  | 4 | $V_{\text {SS }}$ | $\mathrm{V}_{\text {SS }}$ | VDD | PG1 | VDD | $V_{\text {SS }}$ | $\mathrm{a}_{\mathrm{n}}$ |
|  | 5 | $V_{\text {SS }}$ | $\mathrm{V}_{\text {SS }}$ | VDD | $\mathrm{V}_{\text {SS }}$ | PG1 | $V_{\text {SS }}$ | $\mathrm{O}_{\mathrm{n}}$ |
| PWMR | 4 | VSS | $\mathrm{V}_{\text {SS }}$ | $V_{\text {DD }}$ | PG1 | VDD | $V_{\text {SS }}$ | $\mathrm{Q}_{\mathrm{n}}$ |
| PWPE | 3 | $\mathrm{V}_{\text {SS }}$ | $V_{\text {SS }}$ | PG1 | $V_{S S}$ | PG2 | $V_{S S}$ | $\mathrm{O}_{\mathrm{n}}$ |
| PWC | 1 | PG1 | $\mathrm{V}_{\text {SS }}$ | $V_{\text {SS }}$ | VSS | $V_{\text {SS }}$ | $\mathrm{V}_{\text {SS }}$ | Q1 |
| fmax | 1 | PG1 | $V_{\text {SS }}$ | $\mathrm{V}_{\text {SS }}$ | $V_{\text {SS }}$ | $\mathrm{V}_{\text {SS }}$ | $\mathrm{V}_{\text {SS }}$ | Q1 |
| thold | 3 | $\mathrm{V}_{\text {SS }}$ | $\mathrm{V}_{\text {SS }}$ | PG1 | $V_{\text {SS }}$ | PG2 | $\mathrm{V}_{\text {SS }}$ | $\mathrm{Q}_{\mathrm{n}}$ |
| $\mathrm{tr}_{\mathrm{r}} \mathrm{tff}^{\text {f }}$ | 6 | $\mathrm{V}_{\text {SS }}$ | $\mathrm{V}_{\text {SS }}$ | $V_{\text {SS }}$ | $V_{\text {DD }}$ | $\mathrm{V}_{\text {SS }}$ | PG1 | '0' |
| tPLH, tPHL | 7 | PG | $\mathrm{V}_{\text {SS }}$ | Fig. 1 b | $\mathrm{V}_{\text {SS }}$ | Fig. 16 | VDD | '0' |

## CD4528BM/CD4528BC Dual Monostable Multivibrator

## General Description

The CD4528B is a dual monostable multivibrator. Each device is retriggerable and resettable. Triggering can occur from either the rising or falling edge of an input pulse, resulting in an output pulse over a wide range of widths. Pulse duration and accuracy are determined by external timing components $\mathrm{R}_{\mathrm{X}}$ and $\mathrm{C}_{\mathrm{X}}$.

## Features

- Wide supply voltage range 3.0 V to 18 V
- Separate reset available
- Quiescent current $=5.0 \mathrm{nA} /$ package (typ.) at $5.0 \mathrm{~V}_{\mathrm{DC}}$
- Diode protection on all inputs
- Triggerable from leading or trailing edge pulse
- Capable of driving two low-power TTL loads or one low-power Schottky TTL load over the rated temperature range


## Connection Diagrams



Truth Tables

| Inputs |  |  | Outputs |  |
| :---: | :---: | :---: | :---: | :---: |
| Clear | A | B | Q | Q |
| L | X | X | L | H |
| X | H | X | L | H |
| X | X | L | L | H |
| H | L | $\downarrow$ | $\Omega$ | I |
| H | $\uparrow$ | H | $\Omega$ | U |

# Absolute Maximum Ratings 

VDD, DC Supply Voltage
VIN, Input Voltage, All Inputs
TS, Storage Temperature Range
$P_{D}$, Package Dissipation
$T_{L}$, Lead Temperature (soldering, 10 seconds) $300^{\circ} \mathrm{C}$

Recommended Operating Conditions

VDD. DC Supply Voltage
VIN, Input Voltage
$\mathrm{T}_{\mathrm{A}}$, Operating Temperature Range CD4528BM CD4528BC

3 V to 15 V
$O V$ to $V_{D D} V_{D C}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

DC Electrical Characteristics CD4528BM
(Note 2)

| Parameter | Conditions | $-55^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Typ | Max | Min | Max |  |
| IDD Quiescent Device Current | $V_{D D}=5 \mathrm{~V}$ |  | 5 | 0.005 |  | 5 |  | 150 | $\mu \mathrm{A}$ |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 10 | 0.010 |  | 10 |  | 300 | $\mu \mathrm{A}$ |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 20 | 0.015 |  | 20 |  | 600 | $\mu \mathrm{A}$ |
| VOL Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
|  | $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ High Level Output Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10.0 |  | 9.95 |  | v |
|  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15.0 |  | 14.95 |  | v |
| VIL Low Level Input Voltage | $\mathrm{V}_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  | $V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V}$ |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | $v$ |
|  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  |  |  | 6.75 | 4.0 |  | 4.0 | v |
| $\mathrm{V}_{1} \mathrm{H}$ High Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | v |
|  | $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | v |
|  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | $v$ |
| IOL Low Level Output Current | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4. | 8.8 |  | 2.4 |  | mA |
| IOH High Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=4.6 \mathrm{~V}$ | -0.25 |  | -0.2 | -0.36 |  | -0.14 |  | mA |
|  | $V_{D D}=10 \mathrm{~V}, V_{0}=9.5 \mathrm{~V}$ | -0.62 |  | -0.5 | -0.9 |  | -0.35 |  | mA |
|  | $\mathrm{V}_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -1.8 |  | -1.5 | -3.5 |  | -1.1 |  | mA |
| IIN Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |


| Parameter | Conditions' | $-40^{\circ} \mathrm{C}$ |  | $+25^{\circ} \mathrm{C}$ |  |  | $+85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Typ | Max | Min | Max |  |
| IDD Quiescent Device Current | $V_{D D}=5 \mathrm{~V}$ |  | 20 |  | 0.005 | 20 |  | 150 | $\mu A$ |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.010 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 0.015 | 80 |  | 600 | $\mu \mathrm{A}$ |
| VOL Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  |  | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10.0 |  | 9.95 |  | V |
|  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15.0 |  | 14.95 |  | V |
| VIL Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  | $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | V |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| VIH High Level Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | V |
|  | $\mathrm{V}_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ or 4.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| IOL Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 0.52 |  | 0.44 | 0.88 |  | 0.36 |  | mA |
|  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{O}=1.5 \mathrm{~V}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| ${ }^{\prime} \mathrm{OH}$ High Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.2 |  | -0.16 | -0.36 |  | -0.12 |  | mA |
|  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -0.5 |  | -0.4 | -0.9 |  | -0.3 |  | mA |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -1.4 |  | -1.2 | -3.5 |  | -1.0 |  | mA |
| IIN Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

## AC Electrical Characteristics CD4528BM

$T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, R_{\mathrm{L}}=200 \mathrm{k} \Omega$, Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified.

| Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Output Rise Time | $\begin{aligned} & \mathrm{t}_{\mathrm{r}}=(3.0 \mathrm{~ns} / \mathrm{pF}) C_{\mathrm{L}}+30 \mathrm{~ns}, V_{D D}=5.0 \mathrm{~V} \\ & \mathrm{t}_{\mathrm{r}}=(1.5 \mathrm{~ns} / \mathrm{pF}) \mathrm{C}_{\mathrm{L}}+15 \mathrm{~ns}, V_{D D}=10.0 \mathrm{~V} \\ & \mathrm{t}_{\mathrm{r}}=(1.1 \mathrm{~ns} / \mathrm{pF}) C_{\mathrm{L}}+10 \mathrm{~ns}, V_{D D}=15.0 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 180 \\ & 90 \\ & 65 \end{aligned}$ | $\begin{aligned} & 400 \\ & 200 \\ & 160 \end{aligned}$ | ns <br> ns ns |
| Output Fall Time | $\begin{aligned} & \mathrm{t}_{\mathrm{f}}=(1.5 \mathrm{~ns} / \mathrm{pF}) \mathrm{C}_{\mathrm{L}}+25 \mathrm{~ns}, \mathrm{~V}_{\mathrm{DD}}=5.0 \mathrm{~V} \\ & \mathrm{t}_{\mathrm{f}}=(0.75 \mathrm{~ns} / \mathrm{pF}) \mathrm{C}_{\mathrm{L}}+12.5 \mathrm{~ns}, V_{D D}=10.0 \mathrm{~V} \\ & \mathrm{t}_{\mathrm{f}}=(0.55 \mathrm{~ns} / \mathrm{pF}) \mathrm{C}_{\mathrm{L}}+9.5 \mathrm{~ns}, V_{D D}=15.0 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 50 \\ & 35 \end{aligned}$ | $\begin{aligned} & 200 \\ & 100 \\ & 80 \end{aligned}$ | ns <br> ns ns |
| Turn-Off, Turn-On Delay A or B to Q or $\overline{\mathrm{Q}}$ $C x=15 \mathrm{pF}, \mathrm{Rx}=5.0 \mathrm{k} \Omega$ | $\begin{aligned} & \mathrm{tPLH}, \mathrm{tPHL}=(1.7 \mathrm{~ns} / \mathrm{pF}) \mathrm{C}_{\mathrm{L}}+240 \mathrm{~ns}, \mathrm{~V}_{\mathrm{DD}}=5.0 \mathrm{~V} \\ & \mathrm{tPLH}, \mathrm{tPHL}=(0.66 \mathrm{~ns} / \mathrm{pF}) \mathrm{C}_{\mathrm{L}}+8 \mathrm{~ns}, \mathrm{~V}_{\mathrm{DD}}=10.0 \mathrm{~V} \\ & \mathrm{tPLH}, \mathrm{tPHL}=(0.5 \mathrm{~ns} / \mathrm{pF}) \mathrm{C}_{\mathrm{L}}+65 \mathrm{~ns}, \mathrm{~V}_{\mathrm{DD}}=15.0 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 230 \\ & 100 \\ & 65 \end{aligned}$ | $\begin{aligned} & \hline 500 \\ & 250 \\ & 150 \end{aligned}$ | ns <br> ns <br> ns |
| Turn-Off, Turn-On Delay A or B to Q or $\overline{\mathrm{D}}$ $C x=100 \mathrm{pF}, \mathrm{Rx}=10 \mathrm{k} \Omega$ | $\begin{aligned} & \mathrm{tPLH}, \mathrm{tPHL}=1.7 \mathrm{~ns} / \mathrm{pF}) \mathrm{C}_{\mathrm{L}}+620 \mathrm{~ns}, \mathrm{~V}_{\mathrm{DD}}=5.0 \mathrm{~V} \\ & \mathrm{tPLH}, \mathrm{tPHL}=0.66 \mathrm{~ns} / \mathrm{pF}) \mathrm{C}_{\mathrm{L}}+257 \mathrm{~ns}, \mathrm{~V}_{\mathrm{DD}}=10.0 \mathrm{~V} \\ & \mathrm{tPLH}, \mathrm{tPHL}=(0.5 \mathrm{~ns} / \mathrm{pF}) \mathrm{C}_{\mathrm{L}}+185 \mathrm{~ns}, \mathrm{~V}_{\mathrm{DD}}=15.0 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 230 \\ & 100 \\ & 65 \end{aligned}$ | $\begin{aligned} & 500 \\ & 250 \\ & 150 \end{aligned}$ | ns <br> ns <br> ns |
| Minimum Input Pulse Width <br> A or B $\begin{aligned} & C x=15 \mathrm{pF}, \mathrm{Rx}=5.0 \mathrm{k} \Omega \\ & \mathrm{Cx}=1000 \mathrm{pF,Rx}=10 \mathrm{k} \Omega \end{aligned}$ | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10.0 \mathrm{~V} \\ & V_{D D}=15.0 \mathrm{~V} \\ & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10.0 \mathrm{~V} \\ & V_{D D}=15.0 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 60 \\ & 20 \\ & 20 \\ & 60 \\ & 20 \\ & 20 \end{aligned}$ | $\begin{array}{\|l} \hline 150 \\ 50 \\ 50 \\ \hline 150 \\ 50 \\ 50 \end{array}$ | ns <br> ns <br> ns $\qquad$ <br> ns <br> ns <br> ns |
| Output Pulse Width Q or Q <br> For $\mathrm{Cx}<0.01 \mu \mathrm{~F}$ (see graph for appropriate $V_{D D}$ level) $C x=15 \mathrm{pF}, \mathrm{Rx}=5.0 \mathrm{k} \Omega$ <br> For $\mathrm{Cx}>0.01 \mu \mathrm{~F}$ use $P W_{\text {out }}=0.2 R \times C \times \ln \left[V_{D D}-V_{S S}\right]$ $C x=10,000 \mathrm{pF}, R \mathrm{R}=10 \mathrm{k} \Omega$ | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10.0 \mathrm{~V} \\ & V_{D D}=15.0 \mathrm{~V} \\ & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10.0 \mathrm{~V} \\ & V_{D D}=15.0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 15 \\ & 10 \\ & 15 \end{aligned}$ | $\begin{aligned} & 550 \\ & 350 \\ & 300 \\ & \hline 29 \\ & 37 \\ & 42 \end{aligned}$ | $\begin{aligned} & 45 \\ & 90 \\ & 95 \end{aligned}$ | ns <br> ns <br> ns $\qquad$ <br> $\mu \mathrm{s}$ <br> $\mu \mathrm{s}$ <br> $\mu \mathrm{s}$ |
| Pulse Width Match Between Circuits in the Same Package $C x=10,000 \mathrm{pF}, \mathrm{Rx}=10 \mathrm{k} \Omega$ | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10.0 \mathrm{~V} \\ & V_{D D}=15.0 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 6 \\ & 8 \\ & 8 \end{aligned}$ | $\begin{aligned} & 25 \\ & 35 \\ & 35 \end{aligned}$ | $\begin{aligned} & \hline \% \\ & \% \\ & \% \end{aligned}$ |
| Reset Propagation Delay, tPLH, tPHL $C x=15 \mathrm{pF}, \mathrm{Rx}=5.0 \mathrm{k} \Omega$ | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10.0 \mathrm{~V} \\ & V_{D D}=15.0 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 325 \\ & 90 \\ & 60 \end{aligned}$ | $\begin{aligned} & 600 \\ & 225 \\ & 170 \end{aligned}$ | ns <br> ns <br> ns |
| $\mathrm{Cx}=1000 \mathrm{pF}, \mathrm{Rx}=10 \mathrm{k} \Omega$ | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10.0 \mathrm{~V} \\ & V_{D D}=15.0 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 7.0 \\ & 6.7 \\ & 6.7 \end{aligned}$ |  | $\mu \mathrm{s}$ <br> $\mu \mathrm{s}$ <br> $\mu \mathrm{s}$ |
| Minimum Retrigger Time $\mathrm{Cx}=15 \mathrm{pF}, \mathrm{Rx}=5.0 \mathrm{k} \Omega$ $C x=1000 \mathrm{pF}, \mathrm{Rx}=10 \mathrm{k} \Omega$ | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10.0 \mathrm{~V} \\ & V_{D D}=15.0 \mathrm{~V} \\ & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10.0 \mathrm{~V} \\ & V_{D D}=15.0 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0 \\ & 0 \\ & 0 \\ & 0 \\ & 0 \\ & 0 \end{aligned}$ |  |  |

Logic Diagram (1/2 of Device Shown)


DUTY CYCLE $=50 \%$

Figure 1. Power Dissipation Test Circuit and Waveforms



Figure 4. Normalized Pulse Width vs Temperature


Figure 5. Pulse Width vs $\mathbf{C x}$

## 7 National Semiconductor <br> CD4529BM/CD4529BC Dual 4-Channel or Single 8-Channel Analog Data Selector

## General Description

The CD4529B is a dual 4-channel or a single 8-channel analog data selector, implemented with complementary MOS (CMOS) circuits constructed with N - and P -channel enhancement mode transistors. Dual 4-channel or 8 -channel mode operation is selected by proper input coding, with outputs $Z$ and $W$ tied together for the single 8 -bit mode. The device is suitable for digital as well as analog applications, including various $1-$ of-4 and 1 -of-8 data selector functions. Since the device is ana$\log$ and bidirectional, it can also be used for dual binary to 1 -of-4 or single binary to 1-of-8 decoder applications.

## Features

- Wide supply voltage range 3.0 V to 15 V
- High noise immunity
- Low quiescent power dissipation
$0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
$0.005 \mu \mathrm{~W} /$ package
(typ.) @ $5.0 V_{D C}$

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## Connection Diagram


Truth Table

| STX | STY | B | A | z | W | Dual4-ChannelMode2 Outputs |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 1 | 1 | 0 | 0 | X0 | Yo |  |
| 1 | 1 | 0 | 1 | $\times 1$ | Y1 |  |
| 1 | 1 | 1 | 0 | X2 | Y2 |  |
| 1 | 1 | 1 | 1 | X3 | Y3 |  |
| 1 | 0 | 0 | 0 | $\times 0$ |  |  |
| 1 | 0 | 0 | 1 | $\times 1$ |  |  |
| 1 | 0 | 1 | 0 | $\times 2$ |  | Single |
| 1 | 0 | 1 | 1 | $\times 3$ |  | 8-Channel Mode |
| 0 | 1 | 0 | 0 | YO |  | 1 Output |
| 0 | 1 | 0 | 1 | Y1 |  | tied together) |
| 0 | 1 | 1 | 0 | Y2 |  |  |
| 0 | 1 | 1 | 1 | Y3 |  |  |
| 0 | 0 | X | X |  | gh |  |
|  |  |  |  | $\underset{\text { rmp }}{\text { ITRI }}$ | dance <br> ATE $\left.{ }^{( }\right)$ |  |

## Logic Diagram



## Absolute Maximum Ratings

Recommended Operating Conditions
(Notes 1 and 2)
$V_{D D}$ DC Supply Voltage
$V_{\text {IN }}$ Input Voltage
$T_{S}$ Storage Temperature Range
PD Package Dissipation
$T_{L}$ Lead Temperature (Soldering, 10 seconds)
-0.5 V to +18 V
-0.5 V to $\mathrm{VDD}+0.5 \mathrm{~V}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW
$300^{\circ} \mathrm{C}$
(Note 2)

| $V_{\text {DD }} D C$ Supply Voltage | 3 Z to 15 V |
| :--- | ---: |
| $V_{\text {IN }}$ Input Voltage | 0 to $V_{D D}$ |
| $T_{A}$ Operating Temperature Range |  |
| CD4529BM | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD4529BC | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

## DC Electrical Characteristics CD4529BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 1.0 |  | 0.001 | 1.0 |  | 60 | $\mu \mathrm{A}$ |
|  |  |  |  | 1.0 |  | 0.002 | 1.0 |  | 60 | $\mu \mathrm{A}$ |
|  |  |  |  | 2.0 |  | 0.003 | 2.0 |  | 120 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $V_{I L}=0 V, V_{I H}=V_{D D} . \\|_{O I}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 005 |  | 0.05 | v |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $V_{I L}=0 \mathrm{~V}, \mathrm{~V}_{1 H}=V_{\text {DD }}, \\| \mathrm{l} \mid<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10.0 |  | 9.95 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15.0 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level Input Voltage (Note 3) | $V_{D D}=5 \mathrm{~V}$ |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| V IH | High Level Input Voltage (Note 3) | $V_{D D}=5 \mathrm{~V}$ | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {IN }}=O V$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |
| RON | ON Resistance | $V_{D D}=5 \mathrm{~V}, V_{S S}=-5 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {IN }}=5 \mathrm{~V}$ |  | 400 |  | 165 | 480 |  | 640 | $\Omega$ |
|  |  | $V_{1 N}=--5 V$ | , | 400 |  | 100 | 480 |  | 640 | $\Omega$ |
|  |  | $V_{1 N}= \pm 0.25 \mathrm{~V}$ |  | 400 |  | 155 | 480 |  | 640 | $\Omega$ |
|  |  | $\mathrm{V}_{\text {DD }}=7.5 \mathrm{~V}, \mathrm{~V}_{\text {SS }}=-7.5 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {IN }}=7.5 \mathrm{~V}$ |  | 240 |  | 135 | 270 |  | 400 | $\Omega$ |
|  |  | $V_{\text {IN }}=-7.5 \mathrm{~V}$ |  | 240 |  | 75 | 270 |  | 400 | $\Omega$ |
|  |  | $V_{\text {IN }}= \pm 0.25 \mathrm{~V}$ |  | 240 |  | 100 | 270 |  | 400 | $\Omega$ |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{S S}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {IN }}=10 \mathrm{~V}$ |  | 400 |  | 165 | 480 |  | 640 | $\Omega$ |
|  |  | $V_{\text {IN }}=0.25 V$ |  | 400 |  | 100 | 480 |  | 640 | $\Omega$ |
|  |  | $V_{I N}=5.6 \mathrm{~V}$ |  | 400 |  | 160 | 480 |  | 640 | $\Omega$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{S S}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{1 N}=15 \mathrm{~V}$ |  | 250 |  | 135 | 270 |  | 400 | $\Omega$ |
|  |  | $V_{\text {IN }}=0.25 \mathrm{~V}$ |  | 250 |  | 75 | 270 |  | 400 | $\Omega$ |
|  |  | $V_{\text {IN }}=9.3 V$ |  | 250 |  | 110 | 270 |  | 400 | $\Omega$ |
| loff | Input to Output Leakage Current | $V_{S S}=-5 V, V_{D D}=5 \mathrm{~V}, V_{I N}=5 \mathrm{~V}$, |  | $\pm 125$ |  | $\pm 0.001$ | $\pm 125$ |  | $\pm 1250$ | nA |
|  |  | $V_{\text {OUT }}=-5 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $\begin{aligned} & V_{S S}=-5 V, V_{D D}=5 V, V_{I N}=-5 V \\ & V_{\text {OUT }}=5 V \end{aligned}$ |  | $\pm 125$ |  | $\pm 0.001$ | $\pm 125$ |  | $\pm 1250$ | $n \mathrm{~A}$ |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{SS}}=-7.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=7.5 \mathrm{~V}, \mathrm{~V}_{I N}=7.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{OUT}}=-7.5 \mathrm{~V} \end{aligned}$ |  | $\pm 250$ |  | $\pm 0.0015$ | $\pm 250$ |  | $\pm 2500$ | nA |
|  |  | $\begin{aligned} & V_{\mathrm{SS}}=-7.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=7.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}}=-7.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=7.5 \mathrm{~V} \end{aligned}$ |  | $\pm 250$ |  | $\pm 0.0015$ | $\pm 250$ |  | $\pm 2500$ | nA |

DC Electrical Characteristics CD4529BC (Note 2)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \\ & V_{I L}=0 \mathrm{~V}, V_{I H}=V_{D D}, l_{O I}<1 \mu \mathrm{~A} \\ & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 5.0 |  | 0.001 | 5.0 |  | 70 | $\mu \mathrm{A}$ |
|  |  |  |  | 5.0 |  | 0.002 | 5.0 |  | 70 | $\mu \mathrm{A}$ |
|  |  |  |  | 10.0 |  | 0.003 | 10.0 |  | 140 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage |  |  |  |  |  |  |  |  |  |
|  |  |  |  | 0.05 |  |  | 0.05 |  | 0.05 | $v$ |
|  |  |  |  | 0.05 |  |  | 0.05 |  | 0.05 | $v$ |
|  |  |  |  | 0.05 |  |  | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $V_{\text {IL }}=0 V, V_{\text {IH }}=V_{\text {DD }}, \\|_{\text {OI }}<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.00 |  | 4.95 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10.00 |  | 9.95 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ | $14.95$ |  | 14.95 | 15.00 | . | 14.95 |  | v |
| $V_{\text {IL }}$ | Low Level Input Voltage (Note 3) | $V_{D D}=5 \mathrm{~V}$ |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | $v$ |
| $V_{\text {IH }}$ | High Level Input Voltage (Note 3) | $V_{D D}=5 \mathrm{~V}$ | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | $v$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | v |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | -0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |
| RON | ON Resistance | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\text {SS }}=-5 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {IN }}=5 \mathrm{~V}$ |  | 410 |  | 165 | 480 |  | 560 | $\Omega$ |
|  |  | $V_{1 N}=-5 V$ |  | 410 |  | 100 | 480 |  | 560 | $\Omega$ |
|  |  | $V_{1 N}= \pm 0.25 \mathrm{~V}$ |  | 410 |  | 155 | 480 |  | 560 | $\Omega$ |
|  |  | $V_{D D}=7.5 \mathrm{~V}, \mathrm{~V}_{\text {SS }}=-7.5 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {IN }}=7.5 \mathrm{~V}$ |  | 250 |  | 135 | 270 |  | 350 | $\Omega$ |
|  |  | $V_{\text {IN }}=-7.5 \mathrm{~V}$ |  | 250 |  | 75 | 270 |  | 350 | $\Omega$ |
|  |  | $V_{\text {IN }}= \pm 0.25 \mathrm{~V}$ |  | 250 | - | 100 | 270 |  | 350 | $\Omega$ |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{S S}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {IN }}=10 \mathrm{~V}$ |  | 410 |  | 165 | 480 |  | 560 | $\dot{\Omega}$ |
|  |  | $V_{\text {IN }}=0.25 \mathrm{~V}$ |  | 410 |  | 100 | 480 |  | 560 | $\Omega$ |
|  |  | $V_{\text {IN }}=5.6 \mathrm{~V}$ |  | 410 |  | 160 | 480 |  | 560 | $\Omega$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {SS }}=0 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\text {IN }}=15 \mathrm{~V}$ |  | 250 |  | 135 | 270 |  | 350 | $\Omega$ |
|  |  | $V_{\text {IN }}=0.25 \mathrm{~V}$ |  | 250 |  | 75 | 270 |  | 350 | $\Omega$ |
|  |  | $V_{\text {IN }}=9.3 \mathrm{~V}$ |  | 250 |  | 110 | 270 |  | 350 | $\Omega$ |
| IOFF | Input-Output Leakage Current | $V_{S S}=-5 V, V_{D D}=5 V$ |  |  |  |  |  |  |  |  |
|  |  | $V_{\text {IN }}=5 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=-5 \mathrm{~V}$ |  | $\pm 125$ |  | $\pm 0.001$ | $\pm 125$ |  | $\pm 500$ | $n \mathrm{~A}$ |
|  |  | $V_{\text {IN }}=-5 \mathrm{~V}, V_{\text {OUT }}=5 \mathrm{~V}$ |  | $\pm 125$ |  | $\pm 0.001$ | $\pm 125$ |  | $\pm 500$ | nA |
|  |  | $\mathrm{V}_{\mathrm{SS}}=-7.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=7.5 \mathrm{~V}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\text {IN }}=7.5 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=-7.5 \mathrm{~V}$ |  | $\pm 250$ |  | $\pm 0.0015$ | $\pm 250$ |  | $\pm 1000$ | nA |
|  |  | $V_{\text {IN }}=-7.5 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=7.5 \mathrm{~V}$ |  | $\pm 250$ |  | $\pm 0.0015$ | $\pm 250$ |  | $\pm 1000$ | nA |

Note 1: "Absoiute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $V_{S S}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: Switch OFF is defined as $\| \mathrm{O} \mid \leq 10 \mu \mathrm{~A}$, switch ON as defined by $\mathrm{R}_{\mathrm{ON}}$ specification.

## AC Electrical Characteristics CD4529Bm/CD4529BC

$T_{A}=25^{\circ} \mathrm{C}, R_{L}=1 \mathrm{k} \Omega, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPLH. TPHL | $V_{\text {IN }}$ to VOUT Propagation Delay | $V_{S S}=0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 20 | 40 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 10 | 20 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 8 | 15 | ns |
| tPLH, tPHL | Control to Output Propagation Delay | $\begin{aligned} & V_{I N}=V_{D D} \text { or } V_{S S}, C_{L}=50 \mathrm{pF} \\ & V_{I N} \leq 10 \mathrm{~V} \end{aligned}$ |  |  |  |  |
|  | . | $V_{D D}=5 \mathrm{~V}$ |  | 200 | 400 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 80 | 160 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 50 | 120 | ns |
| fmAX | Maximum Control Input Pulse Frequency | $V_{S S}=0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 5 |  | MHz |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  | MHz |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 12 |  | MHz |
|  | Crosstalk, Control to Output | $\mathrm{R}_{\text {OUT }}=10 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{V}_{\mathrm{SS}}=0$ |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 5.0 |  | $m V$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 5.0 |  | $m V$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 5.0 |  | mV |
|  | Noise Voltage | $f=100 \mathrm{~Hz}, V_{S S}=0 \mathrm{~V}$ |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 24 |  | $n \mathrm{~V} / \sqrt{\text { cycle }}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 25 |  | $n \mathrm{~V} / \sqrt{\text { cycle }}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 30 |  | $n \mathrm{~V} / \sqrt{\text { cycle }}$ |
|  |  | $f=100 \mathrm{kHz}, V_{S S}=0 \mathrm{~V}$ |  |  |  |  |
|  |  | $V_{D D}=5 \mathrm{~V}$ |  | 12 |  | $n \mathrm{~V} / \sqrt{\text { cycle }}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 12 |  | $n \mathrm{~V} / \sqrt{\text { cycle }}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 15 |  | $n \mathrm{~V} / \sqrt{\text { cycle }}$ |
|  | Sine Wave (Distortion) | $\begin{aligned} & V_{I N}=1.77 \mathrm{Vrms} \text { Centered } \\ & \text { at } 0 \mathrm{~V}, R_{\mathrm{L}}=10 \mathrm{k} \Omega, f=1 \mathrm{kHz}, \\ & V_{S S}=-5 \mathrm{~V}, V_{D D}=5 \mathrm{~V} \end{aligned}$ |  | 0.36 |  | \% |
| 'LOSS | Insertion Loss, VI, | $\mathrm{V}_{\text {IN }}=1.77 \mathrm{Vrms}$ Centered <br> at $O \mathrm{~V}, \mathrm{~V}_{S S}=-5 \mathrm{~V}, V_{D D}=5 \mathrm{~V}$ |  |  |  |  |
|  | $\text { LOSS }=20 \log _{10} \frac{V_{\text {OUT }}}{V_{\text {IN }}}$ | $R_{L}=1 \mathrm{k} \Omega$ |  | 2.0 |  | dB |
|  |  | $R_{L}=10 \mathrm{k} \Omega$ |  | 0.8 |  | dB |
|  |  | $R_{L}=100 \mathrm{k} \Omega$ |  | 0.25 |  | dB |
|  |  | $R_{L}=1 \mathrm{M} \Omega$ |  | 0.01 |  | dB |
| BW | Bandwidth, -3 dB | $V_{I N}=1.77 \mathrm{Vrms}$ Centered at $0 \mathrm{Vdc}, \mathrm{V}_{\mathrm{SS}}=-5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  |  |  |  |
|  |  | $R_{L}=1 \mathrm{k} \Omega$ | 35 |  |  | MHz |
|  |  | $R_{L}=10 \mathrm{k} \Omega$ | 28 |  |  | MHz |
|  |  | $R_{L}=100 \mathrm{k} \Omega$ | 27 |  |  | MHz |
|  |  | $R_{L}=1 \mathrm{M} \Omega$ | 26 |  |  | MHz |
|  | Feedthrough and Crosstalk,$20 \log _{10} \frac{V_{\text {OUT }}}{V_{\text {IN }}}=-50 \mathrm{~dB}$ | $V_{S S}=-5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  |  |  |  |
|  |  | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ | 850 |  |  | kHz |
|  |  | $R_{L}=10 \mathrm{k} \Omega$ | 100 |  |  | kHz |
|  |  | $R_{L}=100 \mathrm{k} \Omega$ | 12 |  |  | $\mathrm{kHz}^{2}$ |
|  |  | $R_{L}=1 \mathrm{M} \Omega$ | 1.5 |  |  | kHz |

## Test Circuits and Switching Time Waveforms



Frequency Response


Propagation Delay



## Typical Performance Characteristics

Typical Insertion Loss/
Bandwidth Characteristics


## CD4538BM/CD4538BC Dual Precision Monostable Multivibrator

## General Description

The CD4538B is a dual, precision monostable multivibrator with independent trigger and reset controls. The device is retriggerable and resettable, and the control inputs are internally latched. Two trigger inputs are provided to allow either rising or falling edge triggering. The reset inputs are active low and prevent triggering while active. Precise control of output pulse-width has been achieved using linear CMOS techniques. The pulse duration and accuracy are determined by external components $R_{X}$ and $C_{X}$. The device does not allow the timing capacitor to discharge through the timing pin on powerdown condition. For this reason, no external protection resistor is required in series with the timing pin. Input protection from static discharge is provided on all pins.

## Features

- Wide supply voltage range 3.0 V to 15 V
- High noise immunity $0.45 \mathrm{~V}_{\mathrm{CC}}$ (typ.)
- Low power
fan out of 2 driving 74L
or 1 driving 74LS
. New Formula: PW $_{\text {OUT }}=$ RC
(PW in seconds, R in Ohms, C in Farads)
- $\pm 1.0 \%$ pulse-width variation from part to part (typ.)
- Wide pulse-width range $1 \mu \mathrm{~s}$ to $\infty$
- Separate latched reset inputs
- Symmetrical output sink and source capability
- Low standby current

5 nA (typ.)
@ $5 \mathrm{~V}_{\mathrm{DC}}$

## Block \& Connection Diagrams



## Truth Table

| Inputs |  |  | Outputs |  |
| :---: | :---: | :---: | :---: | :---: |
| Clear | $A$ | $B$ | $Q$ | $\bar{Q}$ |
| $L$ | $X$ | $X$ | $L$ | $H$ |
| $X$ | $H$ | $X$ | $L$ | $H$ |
| $X$ | $X$ | $L$ | $L$ | $H$ |
| $H$ | $L$ | $\downarrow$ | $\Omega$ | $工$ |
| $H$ | $\uparrow$ | $H$ | $\Omega$ | $U$ |

$H=$ High Level
L = Low Level
$\uparrow=$ Transition from Low to High
$\downarrow=$ Transition from High to Low
$\Omega=$ One High Level Pulse

- = One Low Level Pulse

X = Irrelevant

Absolute Maximum Ratings (Notes 1 and 2)
$V_{D D}$ DC Supply Voltage

$$
\begin{array}{r}
-0.5 \mathrm{~V} \text { to }+18 \mathrm{~V}_{\mathrm{DC}} \\
-0.5 \text { to } \mathrm{VDD}+0.5 \mathrm{VCD} \\
-65^{\circ} \mathrm{C} \text { to }+150^{\circ} \mathrm{C} \\
500 \mathrm{~mW} \\
\text { s) } \\
300^{\circ} \mathrm{C}
\end{array}
$$

$V_{\text {IN }}$ Input Voltage
$\mathrm{T}_{\mathrm{S}}$ Storage Temperature Range
$P_{D}$ Package Dissipation
Recommended Operating Conditions (Note 2)
$V_{D D}$ DC Supply Voltage
$V_{\text {IN }}$ Input Voltage
$T_{A}$ Operating Temperature Range
CD4538BM,
CD4538BC

$$
+3 \text { to }+15 \mathrm{~V}_{\mathrm{DC}}
$$ 0 to $V_{D D} V_{D C}$

$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

DC Electrical Characteristics (Note 2) - CD4538BM

| Parameter |  | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| $I_{\text {DD }}$ | Quiescent |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V} \quad \mathrm{~V}_{\mathrm{IH}}=\mathrm{V}_{\mathrm{DD}}$ |  | 5 |  | 0.005 | 5 |  | 150 | $\mu \mathrm{A}$ |
|  | Device Current | $\left.V_{\text {DD }}=10 \mathrm{~V}\right\} \mathrm{V}_{\mathrm{IL}}=\mathrm{V}_{\text {SS }}$ |  | 10 |  | 0.010 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ All outputs open |  | 20 |  | 0.015 | 20 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \quad \mathrm{~V}_{1 H}=V_{D D}, V_{I L}=V_{S S}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $V_{D D}=5 \mathrm{~V},\left\|{ }^{0}\right\|<1 \mu \mathrm{~A}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}\left\{\begin{array}{l}\left.\left\lvert\, \begin{array}{l}10\end{array}\right.\right)<1 \mu \mathrm{~A} \\ V_{1 H}=V_{D D}\end{array}\right.$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IH}}=\mathrm{V}_{\mathrm{DD}}, \mathrm{V}_{\mathrm{IL}}=\mathrm{V}_{S S}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V. |
| $\mathrm{V}_{\text {IL }}$ | Low Level Input Voltage | $\begin{aligned} & \left\|I_{O}\right\|<1 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V} \end{aligned}$ |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{1 \mathrm{H}}$ | High Level Input Voltage | $\left\|l_{0}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| l OL | Low Level Output Current |  | 0.64 |  | 0.51 | 0.88 |  | 0.36 |  | mA |
|  |  | $V_{\text {DD }}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}, \mathrm{~V}^{\text {d }}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$, $\mathrm{V}_{\text {IL }}=\mathrm{V}_{\text {SS }}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| $\mathrm{IOH}^{\text {l }}$ | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V} \quad V_{1 H}=V_{D D}$ | -0.64 |  | -0.51 | $-0.88$ |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V},{ }^{\text {V }}$ | -1.6 |  | -1.3 | $-2.25$ |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}, \quad \mathrm{~V}_{\text {IL }}=\mathrm{V}_{\text {SS }}$ | -4.2 |  | -3.4 | -8.8 |  | -2.4 |  | mA |
| 1 N | Input Current, pin 2 or 14 | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ or 15 V |  | $\pm 0.02$ |  | $\pm 10^{-5}$ | $\pm 0.05$ |  | $\pm 0.5$ | $\mu \mathrm{A}$ |
| 1 N | Input Current, other inputs | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V}$ or 15 V |  | $\pm 0.1$ |  | $\pm 10^{-5}$ | $\pm 0.1$ |  | $\pm 1.0$ | $\mu \mathrm{A}$ |

DC Electrical Characteristics (Note 2) - CD4538BC

| Parameter |  | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IDD | Quiescent |  | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{1 H}=\mathrm{V}_{\mathrm{DD}}$ |  | 20 |  | 0.005 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  | Device Current | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.010 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ All outputs open |  | 80 |  | 0.015 | 80 |  | 600 | $\mu \mathrm{A}$ |
| VOL |  | $V_{D D}=5 \mathrm{~V},\left\|\mathrm{I}_{0}\right\|<1 \mu \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  | Output Voltage | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V} \int V_{I H}=V_{D D}, V_{I L}=V_{S S}$ |  |  |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level | $V_{D D}=5 \mathrm{~V},\left\|V_{0}\right\|<1 \mu \mathrm{~A}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | V |
|  | Output Voltage | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$, $\mathrm{V}_{\text {IH }}=V_{\text {DD }}, V_{I L}=V_{S S}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level | $\left\|I_{0}\right\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  | Input Voltage | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V}$ |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.50 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High Level | $\|10\|<1 \mu \mathrm{~A}$ |  |  |  |  |  |  | . |  |
|  | Input Voltage | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V}$ |  |  |  |  |  | 3.5 |  |  |
|  |  | $V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V}$ | 7.0 |  | 7.0 | 5.50 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{0}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| lol | Low Level | $\left.V_{D D}=5 \mathrm{~V}, \quad V_{O}=0.4 \mathrm{~V}\right) V_{I H}=V_{D D}$ |  |  |  | 0.88 |  | 0.36 |  | mA |
|  | Output Current | $V_{D D}=10 \mathrm{~V}, V_{O}=0.5 \mathrm{~V}, V_{I H}=V_{D D}$ | 1.3 |  | 1.1 | 2.25 |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=1.5 \mathrm{~V} \int^{V_{I L}}=V_{S S}$ | 3.6 |  | 3.0 | 8.8 |  | 2.4 |  | mA |
| IOH |  |  | -0.52 |  | -0.44 | $-0.88$ |  | -0.36 |  | mA |
|  | Output Current | $V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V}, \begin{aligned} & V_{I H}=V_{D D} \\ & V_{11}=V_{S C} \end{aligned}$ | -1.3 |  | -1.1 | $-2.25$ |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~L}}=V_{S S}$ | -3.6 |  | -3.0 | -8.8 |  | -2.4 |  | mA |
| IIN | Input Current, pin 2 or 14 | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ or 15 V |  | $\pm 0.02$ |  | $\pm 10^{-5}$ | $\pm 0.05$ |  | $\pm 0.5$ | $\mu \mathrm{A}$ |
| 1 N | Input Current, other inputs | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V}$ or 15 V |  | $\pm 0.3$ |  | $\pm 10^{-5}$ | $\pm 0.3$ |  | $\pm 1.0$ | $\mu \mathrm{A}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.

AC Electrical Characteristics $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, and $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$ unless otherwise specified.

| Parameter |  | Conditions |  | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {TLH }}, \mathrm{t}_{\text {THL }}$ | Output Transition Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  |  | 100 50 40 | $\begin{array}{r} 200 \\ 100 \\ 80 \end{array}$ | ns ns ns |
| $\mathrm{t}_{\text {PLH }}, \mathrm{t}_{\text {PHL }}$ | Propagation Delay Time | Trigger Opera A or B to Q or $V_{D D}=5 \mathrm{~V}$ <br> $V_{D D}=10 \mathrm{~V}$ <br> $V_{D D}=15 \mathrm{~V}$ |  |  | 300 150 100 | 600 300 220 | ns ns ns |
|  |  | Reset Operat $C_{D}$ to $Q$ or $\bar{Q}$ $V_{D D}=5 \mathrm{~V}$ <br> $V_{D D}=10 \mathrm{~V}$ <br> $V_{D D}=15 \mathrm{~V}$ |  |  | 250 125 95 | 500 250 190 | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {WL }}, t_{\text {WH }}$ | Minimum Input Pulse Width $A, B$, or $C_{D}$ | $\begin{aligned} & V_{D D}=5 V \\ & V_{D D}=10 V \\ & V_{D D}=15 V \end{aligned}$ |  |  | 35 30 25 | $\begin{aligned} & 70 \\ & 60 \\ & 50 \end{aligned}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {RR }}$ | Minimum Retrigger Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  |  | 0 | $\begin{aligned} & 0 \\ & 0 \\ & 0 \end{aligned}$ | ns ns $n s$ |
|  | Input Capacitance | Pin 2 or 14 other inputs |  |  | $\begin{gathered} 10 \\ 5 \end{gathered}$ | 7.5 | $\begin{aligned} & \mathrm{pF} \\ & \mathrm{pF} \end{aligned}$ |
| PWOUT | Output Pulse Width ( Q or $\overline{\mathrm{Q}}$ ) <br> (Note: For typical distribution, see Figure 9) | $\begin{aligned} & \mathrm{R}_{\mathrm{X}}=100 \mathrm{k} \Omega \\ & \mathrm{C}_{\mathrm{X}}=0.002 \mu \mathrm{~F} \end{aligned}$ | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 208 \\ & 211 \\ & 216 \end{aligned}$ | 226 230 235 | $\begin{aligned} & 244 \\ & 248 \\ & 254 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \\ & \mu \mathrm{~S} \end{aligned}$ |
|  |  | $\begin{aligned} & \mathrm{R}_{\mathrm{X}}=100 \mathrm{k} \Omega \\ & \mathrm{C}_{\mathrm{X}}=0.1 \mu \mathrm{~F} \end{aligned}$ | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 8.83 \\ & 9.02 \\ & 9.20 \end{aligned}$ | 9.60 9.80 10.00 | $\begin{aligned} & 10.37 \\ & 10.59 \\ & 10.80 \end{aligned}$ | ms <br> ms <br> ms |
|  |  | $\begin{aligned} & R_{x}=100 \mathrm{k} \Omega \\ & \mathrm{C}_{\mathrm{X}}=10.0 \mu \mathrm{~F} \end{aligned}$ | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 0.87 \\ & 0.89 \\ & 0.91 \end{aligned}$ | 0.95 0.97 0.99 | $\begin{aligned} & 1.03 \\ & 1.05 \\ & 1.07 \end{aligned}$ | $\begin{aligned} & \mathrm{s} \\ & \mathrm{~s} \\ & \mathrm{~s} \end{aligned}$ |
| Pulse Width Match between circuits in the same package $\mathrm{C}_{\mathrm{X}}=0.1 \mu \mathrm{~F}, \mathrm{R}_{\mathrm{X}}=100 \mathrm{k} \Omega$ |  | $\begin{aligned} & \mathrm{R}_{\mathrm{X}}=100 \mathrm{k} \Omega \\ & \mathrm{C}_{\mathrm{X}}=0.1 \mu \mathrm{~F} \end{aligned}$ | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\pm 1$ $\pm 1$ $\pm 1$ |  | $\begin{aligned} & \% \\ & \% \\ & \% \end{aligned}$ |
| Operating Conditions |  |  |  |  |  |  |  |
| $\begin{array}{ll}R_{X} & \text { External Timing Resistance } \\ C_{X} & \text { External Timing Capacitance }\end{array}$ |  |  |  | $\begin{gathered} 5.0 \\ 0 \end{gathered}$ |  | No Limit | $\mathrm{k} \Omega$ pF |

*The maximum usable resistance $R_{X}$ is a function of the leakage of the Capacitor $C_{x}$, leakage of the CD4538B, and leakage due to board layout, surface resistance, etc.
Logic Diagram


Figure 1.

## Theory of Operation



Figure 2.

## Trigger Operation

The block diagram of the CD4538B is shown in Figure 1, with circuit operation following.

As shown in Figures 1 and 2, before an input trigger occurs, the monostable is in the quiescent state with the $Q$ output low, and the timing capacitor $\mathrm{C}_{X}$ completely charged to $V_{D D}$. When the trigger input $A$ goes from $V_{S S}$ to $V_{D D}$ (while inputs $B$ and $C_{D}$ are held to $V_{D D}$ ) a valid trigger is recognized, which turns on comparator C 1 and N -Channel transistor $\mathrm{N} 1{ }^{(1)}$. At the same time the output latch is set. With transistor N1 on, the capacitor $\mathrm{C}_{\mathrm{X}}$ rapidly discharges toward $\mathrm{V}_{\mathrm{SS}}$ until $\mathrm{V}_{\text {REF } 1}$ is reached. At this point the output of comparator C1 changes state and transistor N1 turns off. Comparator C1 then turns off while at the same time comparator C 2 turns on. With transistor N 1 off, the capacitor $\mathrm{C}_{\mathrm{X}}$ begins to charge through the timing resistor, $\mathrm{R}_{\mathrm{X}}$, toward $\mathrm{V}_{\mathrm{DD}}$. When the voltage across $C_{X}$ equals $V_{\text {REF2 }}$, comparator $C 2$ changes state causing the output latch to reset (Q goes low) while at the same time disabling comparator C2. This ends the timing cycle with the monostable in the quiescent state, waiting for the next trigger.

A valid trigger is also recognized when trigger input $B$ goes from $V_{D D}$ to $V_{S S}$ (while input $A$ is at $V_{S S}$ and input $\mathrm{C}_{\mathrm{D}}$ is at $\left.\mathrm{V}_{\mathrm{DD}}\right)^{(2)}$.

It should be noted that in the quiescent state $C_{X}$ is fully charged to $\mathrm{V}_{\mathrm{DD}}$ causing the current through resistor $\mathrm{R}_{\mathrm{X}}$ to be zero. Both comparators are "off" with the total device current due only to reverse junction leakages. An added feature of the CD4538B is that the output latch is
set via the input trigger without regard to the capacitor voltage. Thus, propagation delay from trigger to $Q$ is independent of the value of $\mathrm{C}_{\mathrm{x}}, \mathrm{R}_{\mathrm{x}}$, or the duty cycle of the input waveform.

## Retrigger Operation

The CD4538B is retriggered if a valid trigger occurs(3)followed by another valid trigger (4) before the Q output has returned to the quiescent (zero) state. Any retrigger, after the timing node voltage at pin 2 or 14 has begun to rise from $V_{\text {REF1 }}$, but has not yet reached $V_{\text {REF2 }}$, will cause an increase in output pulse width T . When a valid retrigger is initiated (4), the voltage at T2 will again drop to $\mathrm{V}_{\mathrm{REF} 1}$ before progressing along the RC charging curve toward $V_{D D}$. The $Q$ output will remain high until time T , after the last valid retrigger.

## Reset Operation

The CD4538B may be reset during the generation of the output pulse. In the reset mode of operation, an input pulse on $C_{D}$ sets the reset latch and causes the capacitor to be fast charged to $\mathrm{V}_{\mathrm{DD}}$ by turning on transistor Q1 (5). When the voltage on the capacitor reaches $\mathrm{V}_{\text {REF2 }}$, the reset latch will clear and then be ready to accept another pulse. If the $C_{D}$ input is held low, any trigger inputs that occur will be inhibited and the $Q$ and $\bar{Q}$ outputs of the output latch will not change. Since the Q output is reset when an input low level is detected on the $C_{D}$ input, the output pulse T can be made significantly shorter than the minimum pulse width specification.


Figure 3. Retriggerable Monostables Circuitry


Figure 4. Non-retriggerable Monostables Circuitry


Figure 5. Connection of Unused Sections


Figure 6. Switching Test Waveforms


INPUT CONNECTIONS

| CHARACTERISTICS | CD | A | B |
| :--- | :---: | :---: | :---: |
| tPLH, tPHL, tTLH, TTHL, <br> PWOUT, tWH, tWL | VDD | PG1 | VDD |
| TPLH, tPHL, TTLH, tTHL, <br> PWOUT, tWH, tWL | VDD | VSS | PG2 |
| tPLH(R), tPHL(R), <br> tWH, tWL | PG3 | PG1 | PG2 |

*INCLUDES CAPACITANCE OF PROBES, WIRING, AND FIXTURE PARASITIC

NOTE: SWITCHING TEST WAVEFORMS FOR PG1, PG2, PG3 ARE SHOWN IN FIGURE 6.

PG1 $=$


$P G 3=$


Figure 7. Switching Test Circuit



DUTY CYCLE $=50 \%$

Figure 8. Power Dissipation Test Circuit and Waveforms


Figure 9. Typical Normalized Distribution of Units for Output Pulse Width


Figure 10. Typical Pulse Width Variation as a Function of Supply Voltage $V_{D D}$


Figure 11. Typical Total Supply Current Versus Output Duty Cycle, $\mathrm{R}_{\mathrm{X}}=100 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, $\mathrm{C}_{\mathrm{x}}=100 \mathrm{pF}$, One Monostable Switching Only


Figure 12. Typical Pulse Width Error Versus Temperature


Figure 13. Typical Pulse Width Error Versus Temperature


Figure 14. Typical Pulse Width Versus Timing RC Product

## CD4541BM/CD4541BC Programmable Timer

## General Description

The CD4541B Programmable Timer is designed with a 16-stage binary counter, an integrated oscillator for use with an external capacitor and two resistors, output control logic, and a special power-on reset circuit. The special features of the power-on reset circuit are first no additional static power consumption and second the part functions across the full voltage range ( $3-15 \mathrm{~V}$ ) whether power-on reset is enabled or disabled.

Timing and the counter are initialized by turning on power, if the power-on reset is enabled. When the power is already on, an external reset pulse will also initialize the timing and counter. After either reset is accomplished, the oscillator frequency is determined by the external RC network. The 16 -stage counter divides the oscillator frequency by any of 4 digitally controlled division ratios.

## Features

- Available division ratios $2^{8}, 2^{10}, 2^{13}$, or $2^{16}$
- Increments on positive edge clock transitions
- Built-in low power RC oscillator ( $\pm 2 \%$ accuracy over temperature range and $\pm 10 \%$ supply and $\pm 3 \%$ over processing @ < 10 kHz )
. Oscillator frequency range $\approx$ DC to 100 kHz
- Oscillator may be bypassed if external clock is available (apply external clock to pin 3)
- Automatic reset initializes all counters when power turns on
- External master reset totally independent of automatic reset operation
© Operates as $2^{n}$ frequency divider or single transition timer
- Q/ $\overline{\mathrm{Q}}$ select provides output logic level flexibility
- Reset (auto or master) disables oscillator during resetting to provide no active power dissipation
- Clock conditioning circuit permits operation with very slow clock rise and fall times
■ Wide supply voltage range -3.0 V to 15 V
© High noise immunity - 0.45 VDD (typ.)
- $5 \mathrm{~V}-10 \mathrm{~V}-15 \mathrm{~V}$ parametric ratings
m Symmetrical output characteristics
- Maximum input leakage $1 \mu \mathrm{~A}$ at 15 V over full temperature range
- High output drive (pin 8) min. one TTL load


## Logic Diagram



Dual-In-Line Package


Absolute Maximum Ratings (Notes 1 \& 2)
Supply Voltage, $\mathrm{V}_{\mathrm{DD}}$
-0.5 to +18 V Input Voltage, $\mathrm{V}_{\mathrm{IN}}$
Storage Temperature Range, $\mathrm{T}_{\mathrm{S}}$
Package Dissipation, $\mathrm{P}_{\mathrm{D}}$ -0.5 to $\mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}$ $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ 500 mW
Lead Temperature, $\mathrm{T}_{\mathrm{L}}$ (soldering, 10 seconds) $300^{\circ} \mathrm{C}$

Recommended Operating Conditions
(Note 2)

| Supply Voltage, $V_{D D}$ | 3 to 15 V |
| :--- | ---: |
| Input Voltage, $V_{\text {IN }}$ | 0 to $V_{D D}$ |
| Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD4541BM | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

DC Electrical Characteristics (Note 2) - CD4541BM

| Parameter | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IDD Quiescent Device Current | $V_{D D}=5 \mathrm{~V}$ |  | 5 |  | 0.005 | 5 |  | 150 | $\mu \mathrm{A}$ |
|  | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  | 0.010 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  | 0.015 | 20. |  | 600 | $\mu \mathrm{A}$ |
| V ${ }_{\text {LL }}$ Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
|  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V} \quad\|\mathrm{IO}\|<1 \mu \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | $v$ |
|  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | v |
| $\mathrm{V}_{\mathrm{OH}}$ High Level Output Voltage | $V_{\text {DD }}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V} \quad \mid \mathrm{lol}<1 \mu \mathrm{~A}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | $v$ |
|  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | v |
| VIL Low Level Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2 | 1.5 |  | 1.5 | v |
|  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4 | 3.0 |  | 3.0 | $v$ |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6 | 4.0 |  | 4.0 | v |
| $\mathrm{V}_{\mathrm{IH}}$ High Level Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  |  |  |  |  |  |  |
|  | $V_{D D}=10 \mathrm{~V}, V_{O}=1.0 \mathrm{~V} \text { or } 9.0 \mathrm{~V}$ | 7.0 |  | 7.0 | 6 |  | 7.0 |  | v |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 9 |  | 11.0 |  | $\checkmark$ |
| IoL Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{0}=0.4 \mathrm{~V}$ | 2.85 |  | 2.27 | 3.6 |  | 1.6 |  | mA |
|  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 4.96 |  | 4.0 | 9.0 |  | 2.8 |  | mA |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 19.3 |  | 15.6 | 34.0 |  | 10.9 |  | mA |
| $\mathrm{I}_{\text {OH }}$ High Level Output Current |  | 7.96 |  | 6.42 | 13.0 |  | 4.49 |  | mA |
|  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | 4.19 |  | 3.38 | 8.0 |  | 2.37 |  | mA |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | 16.3 |  | 13.2 | 30.0 |  | 9.24 |  | mA |
| IN Input Current | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=0 \mathrm{~V}$ |  | -0.10 |  | -10-5 | -0.10 |  | -1.0 | $\mu \mathrm{A}$ |
|  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.10 |  | $10^{-5}$ | 0.10 |  | 1.0 | $\mu \mathrm{A}$ |

DC Electrical Characteristics (Note 2) - CD4541BC

| Parameter |  | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| $I_{\text {DD }}$ | Quiescent Device Current |  | $V_{D D}=5 \mathrm{~V}$ |  | 20 |  | 0.005 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.010 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 0.015 | 80 |  | 600 | $\mu \mathrm{A}$ |
| VOL Low Level Output Voltage |  | $V_{D D}=5 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V} \quad\left\|\\|_{0}\right\|<1 \mu \mathrm{~A}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ High Level Output Voltage |  | $V_{D D}=5 \mathrm{~V}$ | 4.95 |  | 4.95 | 5 | . | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V} \quad\left\|l_{0}\right\|<1 \mu \mathrm{~A}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level Input Voltage | $V_{\text {DD }}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2 | 1.5 |  | 1.5 | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4 | 3.0 |  | 3.0 | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6 | 4.0 |  | 4.0 | V |
|  | High Level Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 3 |  | 3.5 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 6 |  | 7.0 |  | V |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 9 |  | 11.0 |  | V |
|  | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V}$ | 2.32 |  | 1.96 | 3.6 |  | 1.6 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 3.18 |  | 2.66 | 9.0 |  | 2.18 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 12.4 |  | 10.4 | 34.0 |  | 8.50 |  | mA |

DC Electrical Characteristics (Note 2) - CD4541BC (Cont'd)


AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ (refer to test circuits)

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ${ }^{\text {t }}$ tLH | Output Rise Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 30 \\ & 25 \end{aligned}$ | $\begin{gathered} 200 \\ 100 \\ 80 \end{gathered}$ | $\begin{aligned} & \text { ns } \\ & \text { ns } \\ & \text { ns } \end{aligned}$ |
| $t_{\text {THL }}$ | Output Fall Time | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 30 \\ & 25 \end{aligned}$ | $\begin{gathered} 200 \\ 100 \\ 80 \end{gathered}$ | ns <br> ns <br> ns |
| $t_{\text {plh }}$, $t_{\text {PHL }}$ | Turn-Off, Turn-On Propagation Delay, Clock to Q ( $2^{8}$ Output) | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 1.8 \\ & 0.6 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & 4.0 \\ & 1.5 \\ & 1.0 \end{aligned}$ | $\mu \mathrm{S}$ <br> $\mu \mathrm{S}$ <br> $\mu \mathrm{S}$ |
| $t_{\text {PHL }}$, $t_{\text {PLH }}$ | Turn-On, Turn-Off Propagation Delay, Clock to Q ( $2^{16}$ Output) | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 3.2 \\ & 1.5 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & 8.0 \\ & 3.0 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~S} \\ & \mu \mathrm{~S} \end{aligned}$ |
| $\mathrm{t}_{\mathrm{WH}}(\mathrm{CL})$ | Clock Pulse Width | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 400 \\ & 200 \\ & 150 \end{aligned}$ | $\begin{gathered} 200 \\ 100 \\ 70 \end{gathered}$ |  | ns <br> ns <br> ns |
| $\mathrm{f}_{\mathrm{CL}}$ | Clock Pulse Frequency | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 2.5 \\ & 6.0 \\ & 8.5 \end{aligned}$ | $\begin{aligned} & 1.0 \\ & 3.0 \\ & 4.0 \end{aligned}$ | MHz <br> MHz <br> MHz |
| $\mathrm{t}_{\text {WH(R) }}$ | MR Pulse Width | $\begin{aligned} & V_{D D}=5 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 400 \\ & 200 \\ & 150 \end{aligned}$ | $\begin{aligned} & 170 \\ & 75 \\ & 50 \end{aligned}$ |  | ns ns ns |
| $\mathrm{C}_{1}$ $\mathrm{C}_{\text {PD }}$ | Average Input Capacitance <br> Power Dissipation Capacitance (Note 3) | Any Input |  | $\begin{aligned} & 5.0 \\ & 100 \end{aligned}$ | 7.5 | $\mathrm{pF}$ $\mathrm{pF}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=\mathrm{OV}$ unless otherwise specified.
Note 3: $\mathrm{C}_{P D}$ determines the no load AC power consumption of any CMOS device. For complete explanation, see 54C/74C family characteristics application note AN-90.

| Truth Table |  |
| :--- | :---: |
| Pin State  <br>  0 1 <br> 5 Auto Reset Operating Auto Reset Disabled <br> 6 Timer Operational Master Reset On <br> 9 Output Initially Low <br> after Reset Output Initially High <br> after Reset <br> 10 Single Cycle Mode Recycle Mode |  |

Division Ratio Table

| A | $\mathbf{B}$ | Number of <br> Counter Stages <br> $\mathbf{n}$ | Count <br> $\mathbf{2 n}^{\mathbf{n}}$ |
| :---: | :---: | :---: | :---: |
| 0 | 0 | 13 | 8192 |
| 0 | 1 | 10 | 1024 |
| 1 | 0 | 8 | 256 |
| 1 | 1 | 16 | 65536 |

## Operating Characteristics

With Auto Reset pin set to a＂ 0 ＂the counter circuit is ini－ tialized by turning on power．Or with power already on， the counter circuit is reset when the Master Reset pin is set to a＂1＂．Both types of reset will result in synchro－ nously resetting all counter stages independent of counter state．

The RC oscillator frequency is determined by the external RC network，i．e．：

$$
f=\frac{1}{2.3 R_{t c} C_{t c}} \quad \text { if }(1 \mathrm{kHz} \leqslant f \leqslant 100 \mathrm{kHz})
$$

and $R_{S} \approx 2 R_{t c}$ where $R_{S} \geqslant 10 \mathrm{k} \Omega$
The time select inputs（ A and B ）provide a two－bit address to output any one of four counter stages（ $2^{8}, 2^{10}, 2^{13}$ ，and $2^{16}$ ）．The $2^{n}$ counts as shown in the Division Ratio Table represent the Q output of the Nth stage of the counter． When A is＂ 1 ＂， $2^{16}$ is selected for both states of $B$ ．

However，when B is＂ 0 ＂，normal counting is interrupted and the 9th counter stage receives its clock directly from the oscillator（i．e．，effectively outputting $2^{8}$ ）．

The $Q / \bar{Q}$ select output control pin provides for a choice of output level．When the counter is in a reset condition and $Q / \bar{Q}$ select pin is set to a＂ 0 ＂the $Q$ output is a＂ 0 ＂． Correspondingly，when $Q / \bar{Q}$ select pin is set to a＂ 1 ＂the Q output is a＂ 1 ＂．

When the mode control pin is set to a＂ 1 ＂，the selected count is continually transmitted to the output．But，with mode pin＂ 0 ＂and after a reset condition the RS flip－flop resets（see Logic Diagram），counting commences and after $2^{n-1}$ counts the RS flip－flop sets which causes the output to change state．Hence，after another $2^{n-1}$ counts the output will not change．Thus，a Master Reset pulse must be applied or a change in the mode pin level is required to reset the single cycle operation．

## Power Dissipation Test Circuit and Waveform



## Switching Time Test Circuit and Waveforms



## Oscillator Circuit Using RC Configuration




SOLID LINE $=$ RTC $=56 \mathrm{k} \Omega$, RS $=1 \mathrm{k} \Omega$ AND $\mathrm{C}=1000 \mathrm{pF}$
$f=10.2 \mathrm{kHz} @ V_{D D}=10 \mathrm{~V}$ AND $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
DASHED LINE $=$ RTC $=56 \mathrm{k} \Omega$, $\mathrm{RS}=120 \mathrm{k} \Omega$ AND $\mathrm{C}=1000 \mathrm{pF}$
$\mathrm{f}=7.75 \mathrm{kHz} @ V_{D D}=10 \mathrm{~V}$ AND $\mathrm{T}_{A}=25^{\circ} \mathrm{C}$

RC Oscillator Frequency as a Function of $R_{T C}$ and $C$


LINE A: f AS A FUNCTION OF C AND (RTC $=56 \mathrm{k} \Omega$; RS $=120 \mathrm{k}$ ) LINE B: $f$ AS A FUNCTION OF RTC AND ( $C=1000 \mathrm{pF}$; $\mathrm{RS}=2 \mathrm{RTC}$ )

## CD4543BM/CD4543BC BCD-to-7-Segment Latch/Decoder/Driver for Liquid Crystals

## General Description

The CD4543BM/CD4543BC is a monolithic CMOS BCD-to-7-segment latch/decoder/driver for use with liquid crystal and other types of displays. The circuit provides the functions of a 4-bit storage latch and an 8421 BCD-to-7-segment decoder and driver. The device has the capability to invert the logic levels of the output combination. The phase (Ph), blanking (BI) and latch disable (LD) inputs are used to reverse the truth table phase, blank the display, and store a BCD code, respectively. For liquid crystal (LC) readouts, a square wave is applied to the Ph input of the circuit and the electrically common backplane of the display, and the outputs of the circuit are connected directly to the segments of the LC readout. For other types of readouts, such as light-emitting diode (LED), incandescent, gas discharge, and fluorescent readouts, connection diagrams are given on this data sheet.

All inputs are protected against static discharge by diode clamps to $V_{D D}$ and $V_{S S}$.

## Features

- Wide supply voltage range 3.0 V to 18 V
- High noise immunity
- Low power TTL compatibility
- Low power dissipation $0.45 \mathrm{~V}_{\mathrm{DD}}$ (typ.)
fan out of 2 driving 74 L or 1 driving 74LS
$50 \mathrm{nA} /$ package (typ.)
at $V_{D D}=5.0 \mathrm{~V}$
- Latch storage
- Blanking input
- Blank for all illegal inputs
- Direct-drive LCD, LED and VF displays

Pin-for-pin replacement for CD4056B (with pin 7 tied to $\mathrm{V}_{\mathrm{SS}}$ )
$\pm$ Pin-for-pin replacement for Motorola MC14543B

## Applications

- Instrument (e.g., counter, DVM, etc.) display driver
- Computer/calculator display driver
- Cockput display driver
a Various clock, watch, and timer users

Connection Diagram and Truth Table

Dual-In-Line Package



Display Format


| INPUTS |  |  |  |  |  |  | OUTPUTS |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| LD | BI | Ph* | D | C | B | A | a | b | c | d | e | $f$ | g | DISPLAY |
| X | 1 | 0 | $\times$ | $\times$ | X | $\times$ | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Blank |
| 1 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 |
| 1 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 1 |
| 1 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 2 |
| 1 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 3 |
| 1 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 4 |
| 1 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 5 |
| 1 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 6 |
| 1 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 7 |
| 1 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 8 |
| 1 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 9 |
| 1 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Blank |
| 1 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Blank |
| 1 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Blank |
| 1 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Blank |
| 1 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Blank |
| 1 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Blank |
| 0 | 0 | 0 | X | X | X | X |  |  |  | ** |  |  |  | ** |
| $\dagger$ | † | 1 |  |  | + |  |  | rse | of O | utpu |  |  |  | Display |
|  |  |  |  |  |  |  |  | mbin | atıo | S A | ove |  |  | as Above |

## X = Don't care

$t=$ Above combinations

* $=$ For liquid crystal readouts, apply a square wave to Ph . For common cathode LED readouts, select $\mathrm{Ph}=0$. For common anode LED readouts, select $\mathrm{Ph}=1$.
** $=$ Depends upon the BCD code previously applied when LD $=1$.

Absolute Maximum Ratings
(Notes 1 and 2)

| VDD DC Supply Voltage | -0.5 to $+18 \mathrm{~V}_{\mathrm{DC}}$ |
| :--- | ---: |
| V IN Input Voltage $^{\text {TS Storage Temperature Range }} \quad-0.5$ to $V_{D D}+0.5 \mathrm{VDC}$ |  |
| PD Package Dissipation | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| TL Lead Temperature (Soldering, 10 seconds) | 500 mW |

Recommended Operating Conditions

## (Note 2)

| $V_{D D} D C$ Supply Voltage | $3 V_{D C}$ to $15 V_{D C}$ |
| :--- | ---: |
| $V_{\text {IN }}$ Input $V_{\text {oltage }}$ | 0 to $V_{D D} V_{D C}$ |
| $T_{A}$ Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD4543BM | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

## DC Electrical Characteristics CD4543BM (Note 2)

| PARAMETER |  | CONDITIONS | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| IDD | Quiescent Device Current |  | $\begin{aligned} V_{D D} & =5 \mathrm{~V} \\ V_{D D} & =10 \mathrm{~V} \\ V_{D D} & =15 \mathrm{~V} \end{aligned}$ |  | 5 |  |  | 5 |  | 150 | $\mu \mathrm{A}$ |
|  |  | 10 |  |  |  |  | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | 20 |  |  |  |  | 20 |  | 600 | $\mu \mathrm{A}$ |
| VOL | Low Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ | 0.05 |  |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $\left.V_{D D}=10 \mathrm{~V}\right\}\left\|\mathrm{I}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$. | 0.05 |  |  | 0 | 0.05 |  | 0.05 | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 0.05 |  |  | 0 | 0.05 |  | 0.05 | v |
| VOH | High Level Output Voltage | $V_{D D}=5 \mathrm{~V}$ ) | 4.95 |  | 4.95 | 5 |  | 4.95 |  | v |
|  |  | $\left.V_{D D}=10 \mathrm{~V}\right\}\left\|\mathrm{I}_{\mathrm{O}}\right\|<1 \mu \mathrm{~A}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| $V_{\text {IL }}$ | Low Level Input Voltage | $V_{D D}=5 \mathrm{~V}, ~ V_{O}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  |  | 1.5 |  | 1.5 | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V |  | 3.0 |  |  | 3.0 |  | 3.0 | v |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  |  | 4.0 |  | 4.0 | v |
| $V_{\text {IH }}$ | High Level Input Voltage | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \quad \mathrm{~V}_{0}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 |  |  | 3.5 |  | v |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1 \mathrm{~V}$ or 9 V | 7.0 |  | 7.0 |  |  | 7.0 |  | $v$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 |  |  | 11.0 |  | $v$ |
| IOL | Low Level Output Current | $V_{D D}=5 \mathrm{~V}, ~ V_{0}=0.4 \mathrm{~V}$ | 0.64 |  | 0.51 |  |  | 0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 |  |  | 0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 |  |  | 2.4 |  | mA |
| IOH | High Level Output Current | $V_{D D}=5 \mathrm{~V}, V_{O}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 |  |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 |  |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 |  |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{\text {DD }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

DC Electrical Characteristics CD4543BC (Note 2)


DC Electrical Characteristics CD4543BC (Note 2) (Continued)

| PARAMETER |  | CONDITIONS | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | TYP | MAX | MIN | MAX |  |
| ${ }^{\mathrm{I} O H}$ | High Level Output Current |  | $V_{D D}=5 \mathrm{~V}, \quad V_{O}=4.6 \mathrm{~V}$ | -0.52 |  | -0.44 |  |  | -0.36 |  | mA |
|  |  | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=9.5 \mathrm{~V}$ | -1.3 |  | -1.1 |  |  | -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -3.6 |  | -3.0 |  |  | -2.4 |  | mA |
| IIN | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.3 |  | $-10^{-5}$ | 0.3 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, V_{\text {IN }}=15 \mathrm{~V}$ |  | 0.3 |  | $10^{-5}$ | 0.3 |  | 1.0 | $\mu \mathrm{A}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, \mathrm{V}_{\mathrm{SS}}=0$, unless otherwise specified.

|  | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{r}}$ | Output Rise Time | $V_{D D}=5 V$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| $t_{f}$. | Output Fall Time | $V_{D D}=5 \mathrm{~V}$ |  | 100 | 200 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 50 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 40 | 80 | ns |
| tPLH | Turn-ON Propagation Delay Time | $V_{D D}=5 V$ |  | 450 | 1100 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 170 | 440 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 110 | 330 | ns |
| tPHL | Turn-OFF Propagation Delay Time | $V_{D D}=5 V$ |  | 500 | 1100 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 180 | 440 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 120 | 330 | ns |
| tSET-UP | Set-Up Time | $V_{D D}=5 V$ |  | -5 | 80 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | -2 | 30 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0 | 20 | ns |
| tHOLD | Hold Time | $V_{D D}=5 V$ |  | 30 | 120 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 20 | 45 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 15 | 30 | ns |
| PW LD | Latch Disable Pulse Width | $V_{D D}=5 V$ |  | 50 | 250 | ns |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 30 | 100 | ns |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 | 80 | ns |
| CIN | Input Capacitance | Per Input |  | 5 | 7.5 | pF |
| CPD | Power Dissipation Capacitance | See CPD Measurement Waveforms, (Note 3) |  | 300 |  | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: CPD determines the no load AC power consumption of a CMOS device. For a complete explanation, see "MM54C/74C Family Characteristics" application note AN-90.

## Logic Diagram



## Typical Applications

## Liquid Crystal (LC) Readout

Incandescent Readout


Light Emitting Diode (LED) Readout


Note. Bipolar transistors may be added for gain (for $V_{D D} \leq 10 \mathrm{~V}$ or IOUT $\geq 10 \mathrm{~mA}$ )


3 1/2-Digit DVM with LCD Display


[^25]Switching Time Waveforms


Inputs BI and Ph low, and inputs D and LD high. f in respect to a system clock.
All outputs connected to respective $C_{L}$ loads.

Dynamic Signal Waveforms


## National Semiconductor <br> CD4723BM/CD4723BC Dual 4-Bit Addressable Latch CD4724BM/CD7424BC 8-Bit Addressable Latch

## General Description

The CD4723B is a dual 4-bit addressable latch with common control inputs, including two address inputs (A0, A1), an active low enable input ( E ), and an active high clear input (CL). Each latch has a data input (D) and four outputs (Q0-Q3). The CD4724B is an 8-bit addressable latch with three address inputs (AO-A2), an active low enable input ( $\bar{E}$ ), active high clear input (CL), a data input (D) and eight outputs (Q0-Q7).

Data is entered into a particular bit in the latch when that is addressed by the address inputs and the enable $(\overrightarrow{\mathrm{E}})$ is low. Data entry is inhibited when enable ( $\overline{\mathrm{E}}$ ) is high.

When clear (CL) and enable ( $\overline{\mathrm{E}}$ ) are high, all outputs are low. When clear (CL) is high and enable ( $\bar{E}$ ) is low, the channel demultiplexing occurs. The bit that is addressed has an active output which follows the data input while all unaddressed bits are held low. When operating in the addressable latch mode ( $\bar{E}=C L=$ low), changing more than one bit of the address could
impose a transient wrong address. Therefore, this should only be done while in the memory mode ( $\bar{E}=$ high, $C L=l o w$ ).

## Features

- Wide supply voltage range
3.0 V to 15 V
- High noise immunity
0.45 VDD (typ.)
. Low power TTL compatibility
fan out of 2 driving 74L or 1 driving 74LS

■ Serial to parallel capability

- Storage register capability
( Random (addressable) data entry
- Active high demultiplexing capability
- Common active high clear

CD4723B

top VIEW

CD4724B
Dual-In-Line and Flat Package


TOP VIEW

Truth Table

| MODE SELECTION |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| $\bar{E}$ | CL | ADDRESSED <br> LATCH | UNADDRESSED <br> LATCH | MODE |
| L | L | Follows Data | Holds Previous Data | Addressable Latch |
| H | L | Holds Previous Data | Holds Previous Data | Memory |
| L | H | Follows Data | Reset to "0" | Demultiplexer |
| H | H | Reset to "0" | Reset to "0" | Clear |

## Absolute Maximum Ratings

(Notes 1 and 2)
$\begin{array}{lr}V_{D D} \text { DC Supply Voltage } & -0.5 \text { to }+18 \mathrm{~V}_{\mathrm{DC}} \\ \mathrm{V}_{\text {IN }} \text { Input Voltage } & -0.5 \text { to } \mathrm{V}_{\mathrm{DD}}+0.5 \mathrm{~V}_{D C} \\ \mathrm{~T}_{\mathrm{S}} \text { Storage Temperature Range } & -65^{\circ} \mathrm{C} \text { to }+150^{\circ} \mathrm{C} \\ \mathrm{P}_{\mathrm{D}} \text { Package Dissipation } & 500 \mathrm{~mW} \\ \mathrm{~T}_{\mathrm{L}} \text { Lead Temperature (Soldering, } 10 \text { seconds) } & 300^{\circ} \mathrm{C}\end{array}$

Recommended Operating Conditions
(Note 2)

| $V_{D D} D C$ Supply Voltage | 3.0 to $15 V_{D C}$ |
| :--- | ---: |
| $V_{\text {IN }}$ Input Voltage | 0 to $V_{D D} V_{D C}$ |
| $T_{A}$ Operating Temperature Range |  |
| CD4723BM/CD4724BM | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD4723BC/CD4724BC | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

## DC Electrical Characteristics CD4723BMICD4724BM (Note 2)

| Parameter |  | Conditions | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IDD | Quiescent |  | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  | 5.0 |  | 0.02 | 5.0 |  | 150 | $\mu \mathrm{A}$ |
|  | Device Current | $V_{D D}=10 \mathrm{~V}$ |  | 10 |  | 0.02 | 10 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 20 |  | 0.02 | 20 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {OL }}$ | Low Level | $\left\|l_{0}\right\| \leqslant 1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  | Outpụt Voltage | $V_{D D}=5.0 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level | $\left\|\mathrm{V}_{0}\right\| \leqslant 1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  | Output Voltage | $\mathrm{V}_{\text {DD }}=5.0 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | v |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL | Low Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  | Input Voltage | $\mathrm{V}_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  | $\mathrm{V}_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $\mathrm{V}_{\mathrm{IH}}$ |  | $V_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V} \text { or } 4.5 \mathrm{~V}$ |  |  | 3.5 | 2.75 |  | 3.5 |  |  |
|  | Input Voltage | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  |  | $\mathrm{V}_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |
| loL |  | $V_{D D}=5.0 \mathrm{~V}, V_{O}=0.4 \mathrm{~V}$ |  |  |  | 0.88 |  | 0.36 |  | mA |
|  | Output Current | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=0.5 \mathrm{~V}$ | 1.6 |  | 1.3 | 2.25 |  | 0.9 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ | 4.2 |  | 3.4 | 8.8 |  | 2.4 |  | mA |
| $\mathrm{l}_{\mathrm{OH}}$ | High Level | $\mathrm{V}_{D D}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=4.6 \mathrm{~V}$ | -0.64 |  | -0.51 | -0.88 |  | -0.36 |  | mA |
|  | Output Current | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.6 |  | -1.3 | -2.25 |  | - -0.9 |  | mA |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=13.5 \mathrm{~V}$ | -4.2 |  | -3.4 | -8.8 |  | - 2.4 |  | mA |
| 1 N | Input Current | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | -0.1 |  | $-10^{-5}$ | -0.1 |  | -1.0 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{I}}=15 \mathrm{~V}$ |  | 0.1 |  | $10^{-5}$ | 0.1 |  | 1.0 | $\mu \mathrm{A}$ |

DC Electrical Characteristics CD4723BC/CD4724BC (Note 2)

| Parameter |  | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IDD | Quiescent |  | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  | 20 |  | 0.02 | 20 |  | 150 | $\mu \mathrm{A}$ |
|  | Device Current | $V_{D D}=10 \mathrm{~V}$ |  | 40 |  | 0.02 | 40 |  | 300 | $\mu \mathrm{A}$ |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 80 |  | 0.02 | 80 |  | 600 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level | $\left\|l_{0}\right\| \leqslant 1 \mu \mathrm{~A}$ |  |  |  |  |  |  |  |  |
|  | Output Voltage | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ |  | 0.05 |  | 0 | 0.05 |  | 0.05 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level | $\left\|l_{0}\right\| \leqslant 1 \mu \mathrm{~A}$ |  |  |  | 5 |  |  |  |  |
|  | Output Voltage | $\mathrm{V}_{\text {DD }}=5.0 \mathrm{~V}$ | 4.95 |  | 4.95 | 5.0 |  | 4.95 |  | V |
|  |  | $V_{D D}=10 \mathrm{~V}$ | 9.95 |  | 9.95 | 10 |  | 9.95 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}$ | 14.95 |  | 14.95 | 15 |  | 14.95 |  | V |
| VIL | Low Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5$ or 4.5 V |  | 1.5 |  | 2.25 | 1.5 |  | 1.5 | V |
|  | Input Voltage | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{0}=1.0 \mathrm{~V}$ or 9.0 V |  | 3.0 |  | 4.5 | 3.0 |  | 3.0 | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V |  | 4.0 |  | 6.75 | 4.0 |  | 4.0 | V |
| $V_{\text {IH }}$ | High Level | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ or 4.5 V | 3.5 |  | 3.5 | 2.75 |  | 3.5 |  | V |
|  | Input Voltage | $V_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.0 \mathrm{~V}$ or 9.0 V | 7.0 |  | 7.0 | 5.5 |  | 7.0 |  | V |
|  |  | $V_{D D}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V}$ or 13.5 V | 11.0 |  | 11.0 | 8.25 |  | 11.0 |  | V |

DC Electrical Characteristics (Cont'd.) CD4723BC/CD4724BC (Note 2)

| Parameter |  | Conditions | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |
| IOL | Low Level Output Current |  | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 0.52 \\ 1.3 \\ 3.6 \end{gathered}$ |  | 0.44 1.1 3.0 | $\begin{gathered} \hline 0.88 \\ 2.25 \\ 8.8 \end{gathered}$ |  | $\begin{gathered} 0.36 \\ 0.9 \\ 2.4 \end{gathered}$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $\mathrm{IOH}^{\text {O }}$ | High Level Output Current | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V}, V_{O}=4.6 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V}, V_{O}=9.5 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{O}=13.5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} -0.52 \\ -1.3 \\ -3.6 \end{gathered}$ |  | $\begin{gathered} -0.44 \\ -1.1 \\ -3.0 \end{gathered}$ | $\begin{gathered} -0.88 \\ -2.25 \\ -8.8 \end{gathered}$ |  | $\begin{gathered} -0.36 \\ -0.9 \\ -2.4 \end{gathered}$ |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \\ & \mathrm{~mA} \end{aligned}$ |
|  | Input Current | $\begin{aligned} & V_{D D}=15 \mathrm{~V}, V_{I N}=0 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V}, V_{I N}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{\|c} -0.30 \\ 0.30 \\ \hline \end{array}$ |  | $\begin{array}{r} -10^{-5} \\ 10^{-5} \end{array}$ | $\begin{array}{r} -0.30 \\ 0.30 \\ \hline \end{array}$ |  | $\begin{array}{r} -1.0 \\ 1.0 \end{array}$ | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |

AC Electrical Characteristics $T_{A}=25^{\circ} \mathrm{C}, C_{L}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=200 \mathrm{k}$, Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, unless otherwise noted.

|  | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {PHL }}, \mathrm{t}_{\text {PLH }}$ | Propagation Delay Date to Output | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 200 \\ 75 \\ 50 \end{gathered}$ | $\begin{aligned} & 400 \\ & 150 \\ & 100 \end{aligned}$ |  |
| $t_{\text {PLH }}, t_{\text {PHL }}$ | Propagation Delay Enable to Output | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 200 \\ 80 \\ 60 \end{gathered}$ | $\begin{aligned} & 400 \\ & 160 \\ & 120 \end{aligned}$ | ns ns ns |
| $t_{\text {PHL }}$ | Propagation Delay Clear to Output | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 175 \\ & 80 \\ & 65 \end{aligned}$ | $\begin{aligned} & 350 \\ & 160 \\ & 130 \end{aligned}$ | ns ns ns |
| $t_{\text {PLH }}, t_{\text {PHL }}$ | Propagation Delay Address to Output | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 225 \\ 100 \\ 75 \end{gathered}$ | $\begin{aligned} & 450 \\ & 200 \\ & 150 \end{aligned}$ | ns ns ns |
| $t_{\text {THL }}, t_{\text {TLH }}$ | Transition Time (Any Output) | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 100 \\ & 50 \\ & 40 \end{aligned}$ | $\begin{gathered} 200 \\ 100 \\ 80 \end{gathered}$ | ns <br> ns <br> ns |
| ${ }_{\text {twh }}, T_{\text {WL }}$ | Minimum Data Pulse Width | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 100 \\ 50 \\ 40 \end{gathered}$ | $\begin{gathered} 200 \\ 100 \\ 80 \end{gathered}$ | ns ns ns |
| $t_{\text {WH }}, t_{\text {WL }}$ | Minimum Address Pulse Width | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 200 \\ 100 \\ 65 \end{gathered}$ | $\begin{aligned} & 400 \\ & 200 \\ & 125 \end{aligned}$ | ns ns ns |
| ${ }^{\text {twh }}$ | Minimum Clear Pulse Width | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 75 \\ & 40 \\ & 25 \end{aligned}$ | $\begin{aligned} & 150 \\ & 75 \\ & 50 \end{aligned}$ | ns <br> ns <br> ns |
| tsu | Minimum Set-Up Time Data to $E$ | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 40 \\ & 20 \\ & 15 \end{aligned}$ | $\begin{aligned} & 80 \\ & 40 \\ & 30 \end{aligned}$ | ns ns ns |
| $t_{H}$ | Minimum Hold Time Data to E | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | 60 30 25 | $\begin{aligned} & 120 \\ & 60 \\ & 50 \end{aligned}$ | ns ns ns |
| tsu | Minimum Set-Up. Time Address to E | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=15 \mathrm{~V} \end{aligned}$ |  | -15 0 0 | $\begin{aligned} & 50 \\ & 30 \\ & 20 \end{aligned}$ | ns ns ns |
| $t_{H}$ | Minimum Hold Time Address to E | $\begin{aligned} & V_{D D}=5.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & -50 \\ & -20 \\ & -15 \end{aligned}$ | $\begin{gathered} 15 \\ 10 \\ 5 \end{gathered}$ | ns <br> ns <br> ns |
|  | Power Dissipation Capacitance | Per Package (Note 3) |  | 100 |  | pF |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | Any Input |  | 5.0 | 7.5 | pF |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
Note 2: $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ unless otherwise specified.
Note 3: Dynamic power dissipation ( $P_{D}$ ) is given by: $P_{D}=\left(C_{P D}+C_{L}\right) V_{C C}{ }^{2} f+P_{Q}$; where $C_{L}=$ load capacitance; $f=$ frequency of operation; for further details, see application note AN-90, "54C/74C Family Characteristics".


Logic Diagrams (Cont'd.)


## Switching Time Waveforms



## Section 6

CMOS Compatible Bipolar Interface Circuits

## MM54C909/MM74C909 Quad Comparator

## General Description

The MM54C909/MM74C909 contains four independent bipolar voltage comparators designed to operate from standard 54C/74C power supplies. The output allows current sinking only, thus the wire OR function is possible using a common resistor pull-up.

Not only does the MM54C909/MM74C909 function as a comparator for analog inputs, but also has many applications as a voltage translator and buffer when interfacing the 54C/74C family to other logic systems.

## Features

- Wide supply voltage range
3.0 V to 15 V
- TTL compatibility
- Low power consumption
- Low input bias current
- Low input offset current
- Low input offset voltage
- Large common mode input voltage range
- Large differential input voltage range fan out of 1 driving 74

$$
\mathrm{I}_{\mathrm{CC}}=800 \mu \mathrm{~A} \text { (typ.) }
$$ at $V_{C C}=5.0 V_{D C}$

250 nA max.
$\pm 50$ nA max.
$\pm 5.0 \mathrm{mV}$ max.
0 V to $\mathrm{V}_{\mathrm{CC}}-1.5 \mathrm{~V}$
$V_{C C}$

## Connection Diagram



Typical Applications $\left(\mathrm{v}^{+}=5.0 \mathrm{~V} \mathrm{DC}\right)$


CMOS/TTL to MOS Logic Converter


Ground Referenced Thermocouple in Single Supply System

# Absolute Maximum Ratings <br> (Note 1) 

Voltage at Any Pin
Operating Temperature Range
MM54C909
MM74C909
Storage Temperature Range
Package Dissipation (Notes 2 and 3)
Operating $\mathrm{V}_{\mathrm{Cc}}$ Range
. Absolute Maximum $\mathrm{V}_{\mathrm{cc}}$
Input Current (V $\mathrm{V}_{\text {IN }}<-0.3 \mathrm{~V}$ ) (Note 4)
Lead Temperature (Soldering, 10 seconds)
-0.3 V to $\mathrm{V}_{\mathrm{Cc}}+0.3 \mathrm{~V}$
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
500 mW
3.0 V to 15 V 18 V
50 mA
$300^{\circ} \mathrm{C}$

## DC Electrical Characteristics

$\mathrm{Min} / \mathrm{max}$ limits apply across temperature range, unless otherwise noted. ( $\left.\mathrm{V}_{\mathrm{CC}}=+5.0 \mathrm{~V}_{\mathrm{DC}}\right)$

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Input Offset Voltage (Note 9) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | $\pm 2$ | $\begin{aligned} & \pm 9 \\ & \pm 5 \end{aligned}$ | $\begin{aligned} & m V \\ & m V \end{aligned}$ |
| Input Bias Current ( $I_{\text {IN }(+)}$ or $\left.I_{\text {IN(-) }}\right)$ (Note 5) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, With Output in Linear Range |  | 25 | $\begin{aligned} & 250 \\ & 400 \end{aligned}$ | nA |
| Input Offset Current $\left(I_{\operatorname{IN}(+)}-I_{\operatorname{IN}(-)}\right)$ | $T_{A}=25^{\circ} \mathrm{C}$ |  | $\pm 5$ | $\begin{aligned} & \pm 150 \\ & \pm 50 \end{aligned}$ | nA |
| Input Common Mode Voltage (Note 6) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ |  | $\begin{gathered} V_{C C^{-2}} \\ V_{C C^{-1}} .5 \end{gathered}$ | V |
| Supply Current ( $\mathrm{I}_{\text {cc }}$ ) | $T_{A}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}}=\infty$ <br> On All Outputs . |  | 800 | 2000 | $\mu \mathrm{A}$ |
| Voltage Gain | $T_{A}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}} \geq 15 \mathrm{k} \Omega$ |  | 200 |  | $\mathrm{V} / \mathrm{mV}$ |

OUTPUT DRIVE (See 54C/74C Family Characteristics Data Sheet)

| Output Sink Current ( $\mathrm{I}_{\text {SINK }}$ ) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| MM54C909 | $\mathrm{V}_{\mathrm{CC}}=4.50 \mathrm{~V}$ | 1.6 | 3.2 |  | mA |
| MM74C909 | $\mathrm{V}_{\text {CC }}=4.75 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0.4 \mathrm{~V}$ |  |  |  |  |
|  | $\begin{aligned} & V_{I N(-)} \geq 1.0 V_{D C} \\ & V_{I N(t)}=0 V_{D C} \end{aligned}$ |  |  |  |  |
| Output Leakage Current | $\begin{aligned} & V_{I N(+)} \geq 1.0 V_{D C}, V_{I N(-)}=0 V_{D C} \\ & V_{O U T}=15 V_{D C} \end{aligned}$ |  | - | 1 | $\mu \mathrm{A}$ |
|  | $\begin{aligned} & V_{I N(+)} \geq 1.0 V_{D C}, V_{I N(-)}=0 V_{D C} \\ & V_{O U T}=5 V_{D C}, T_{A}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 0.1 |  | nA |
| Differential Input Voltage (Note 8) | All $V_{\text {IN }}{ }^{\prime} \leq \geq 0 V_{D C}$ |  |  | 15 | V |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: For operating at high temperatures, the MM74C909 must be derated based on $+125^{\circ} \mathrm{C}$ maximum junction temperature and a thermal resistance of $+175^{\circ} \mathrm{C} / \mathrm{W}$ which applies to the device soldered in a printed circuit board, operating in a still air ambient. The MM54C909 must be derated based on a $+150^{\circ} \mathrm{C}$ maximum junction temperature. The low bias dissipation and the ON-OFF characteristic of the outputs keeps the chip dissipation very small ( $\mathrm{Pd} \leq 100 \mathrm{~mW}$ ), provided the output sink current is within specified limits.
Note 3: Short circuits from the output to $\mathrm{V}^{+}$can cause excessive heating and eventual destruction. The maximum output current is approximately 20 mA independent of the magnitude of $\mathrm{V}^{+}$.
Note 4: This input current will only exist when the voltage at any of the input leads is driven negative. There is a lateral NPN parasitic transistor action on the IC chip. The transistor action can cause the output voltages of the comparators to go to the $\mathrm{V}^{+}$voltage level (or to ground for alarge overdrive) for the time duration that an input is driven negative. This is not destructive and normal output states will reestablish when the input voltage, which was negative, again returns to a value greater than -0.3 V .
Note 5: The direction of the input current is out of the IC. This current is essentially constant, independent of the state of the output so no loading change exists on the reference or input lines.
Note 6: The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V . The upper end of the common-mode voltage range is $\mathrm{V}^{+}-1.5 \mathrm{~V}$, but either or both inputs can go to +15 V without damage.
Note 7: The response time specified is for a 100 mV input step with 5.0 mV overdrive. For larger overdrive signals 300 ns can be obtained, see typical performance characteristics section.
Note 8: The positive excursions of the input can equal $V_{C C}$ supply voltage level, and if the other input voltage remains within the common-mode voltage range, the comparator will provide a proper output state. The low input voltage state must not be less than -0.3 V .
Note 9: At output switch point, $V_{O}=1.4 V_{D C}, R_{S}=0 \Omega$ with $V^{+}$from $5 V_{D C}$ to $30 V_{D C}$ and over the full input common mode range ( $0 V_{D C}$ ) to $\left.\mathrm{V}^{+} \pm 1.5 \mathrm{~V}_{\mathrm{DC}}\right)$.

AC Electrical Characteristics $\mathrm{R}_{\mathrm{L}}=5.1 \mathrm{k} \Omega, \mathrm{V}_{\mathrm{RL}}=5.0 \mathrm{~V}_{\mathrm{DC}}$, unless otherwise specified.

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :--- | :---: | :---: | :---: | :---: |
| Large Signal Response Time | $V_{I N}=T T L$ Swing |  | 300 |  | ns |
| Response Time | $\mathrm{V}_{\text {REF }}=1.4 \mathrm{~V}_{\mathrm{DC}}$ |  |  |  |  |

## Typical Performance Characteristics



## application hints

The MM54C909/MM74C909 is a high gain, wide bandwidth device; which, like most comparators, can easily oscillate if the output lead is inadvertently allowed to capacitively couple to the inputs via stray capacitance. This shows up only during the output voltage transition intervals as the comparator changes states. Power supply bypassing is not required to solve this problem. Standard PC board layout is helpful as it reduces stray inputoutput coupling. Reducing the input resistors to $<10 \mathrm{k} \Omega$ reduces the feedback signal levels and finally, adding even a small amount ( 1 to 10 mV ) of positive feedback (hysteresis) causes such a rapid transition that oscillations due to stray feedback are not possible. Simply socketing the I/C and attaching resistors to the pins will cause input-output oscillations during the small transition intervals unless hysteresis is used. If the input signal is a pulse waveform, with relatively fast rise and fall times, hysteresis is not required.

All pins of any unused comparators should be grounded.
The bias network of the MM54C909/MM74C909 establishes an $\mathrm{I}_{\mathrm{CC}}$ current which is independent of the magnitude of the power supply voltage over the range of from 3.0 V to 15 V .

It is usually unnecessary to use a bypass capacitor across the power supply line.

The differential input voltage may be larger than $\mathrm{V}^{+}$ without damaging the device. Protection should be provided to prevent the input voltages from going negative more than $-0.3 \mathrm{~V}_{\mathrm{DC}}$ (at $25^{\circ} \mathrm{C}$ ). An input clamp diode and input resistor can be used as shown in the applications section.

Many outputs can be tied together to provide an output OR'ing function. An output "pull-up" resistor can be connected to any available power supply voltage within the permitted supply voltage range and there is no restriction on this voltage due to the magnitude of the voltage which is applied to the $\mathrm{V}^{+}$terminal of the MM54C909/MM74C909 package. The output can also be used as a simple SPST switch to ground (when a "pull-up" resistor is not used). The amount of current which the output device can sink is limited by the drive available (which is independent of $\mathrm{V}^{+}$) and the gain of the output device. When the maximum current limit is reached (approximately 16 mA ), the output transistor will come out of saturation and the output voltage will rise very rapidly.
typical applications (con't) $\mathrm{v}^{+}=5.0 \mathrm{~V}_{\mathrm{DC}}$ )


Basic Comparator


Driving CMOS


Non-Inverting Comparator with Hysteresis


Note' For non niverting buffer reverse mput connection
Hi Voltage Inverting PMOS to CMOS or TTL

Typical Applications (Cont'd.) $\quad\left(\mathrm{V}^{+}=5.0 \mathrm{VDC}\right)$


MM54C909/MM74C909


Two-Decade High-Frequency VCO


## DS1630/DS3630 Hex CMOS Compatible Buffer

## General Description

The DS1630/DS3630 is a high current buffer intended for use with CMOS circuits interfacing with peripherals requiring high drive currents. The DS1630/DS3630 features low quiescent power consumption (typically $50 \mu \mathrm{~W}$ ) as well as high-speed driving of capacitive loads such as large MOS memories. The design of the DS1630/DS3630 is such that $V_{C C}$ current spikes commonly found in standard CMOS circuits cannot occur, thereby, reducing the total transient and average power when operating at high frequencies.

## Features

- High-speed capacitive driver
- Wide supply voltage range
- Input/output CMOS compatibility
- No internal transient $\mathrm{V}_{\mathrm{CC}}$ current spikes
- $50 \mu \mathrm{~W}$ standby power (typ.)
- Fan out of 10 standard TTL loads


## Equivalent Schematic and Connection Diagrams



## Typical Applications



CMOS to TTL Interface


CMOS To CMOS Interface


Order Number DS 1630, DS3630J or DS3630N


CMOS To Transmission Line Interface


LED Driver

|  |  |  | MIN | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage | 16 V | Supply Voltage ( $\mathrm{V}_{\mathrm{CC}}$ ) | 3 | 15 | $\checkmark$ |
| Input Voltage | 16 V | Temperature ( $\mathrm{TA}_{\text {I }}$ ) |  |  |  |
| Output Voltage | 16 V | DS1630 | -55 | +125 | C |
| Lead Temperature (Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ | DS3630 | 0 | +125 +70 | ${ }^{\circ} \mathrm{C}$ |

DC Electrical Characteristics (Notes 2 and 3 )

| PARAMETER | CONDITIONS |  | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| IINH Logical " 1 " Input Current | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {CC, }} \mathrm{I}_{\text {OUT }}=-400 \mu \mathrm{~A}$ | DS1630 |  | 90 | 200 | $\mu \mathrm{A}$ |
|  |  | DS3630 |  | 90 | 200 | $\mu \mathrm{A}$ |
|  | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\mathrm{CC}}-2.0 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=16 \mathrm{~mA}$ | DS1630 |  | 0.5 | 3.2 | mA |
|  |  | DS3630 |  | 0.5 | 1.5 | mA |
| IINL Logical " 0 " Input Current | $\mathrm{V}_{\text {IN }}=0.4 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=16 \mathrm{~mA}$ | DS1630 |  | -0.15 | -1 | mA |
|  |  | DS3630 |  | $\mathrm{V}_{\mathrm{cc}}-150$ | -800 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OH}}$ Logical "1" Output Voltage | $V_{\text {IN }}=V_{\text {CCI }}, \mathrm{I}_{\text {OUT }}=-400 \mu \mathrm{~A}$ | DS1630 | $\mathrm{V}_{\mathrm{cc}}{ }^{-1}$ | $\mathrm{V}_{\mathrm{cc}}-0.75$ |  | V |
|  |  | DS3630 | $\mathrm{V}_{c c}-0.9$ | $\mathrm{V}_{c c}{ }^{-0.75}$ |  | V |
|  | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {CC }}-0.4 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=16 \mathrm{~mA}$ | DS1630 | $\mathrm{V}_{C c}-2.5$ | $\mathrm{V}_{c c}-2.0$ |  | V |
|  |  | DS3630 | $\mathrm{V}_{C c^{-2.5}}$ | $V_{c c}{ }^{-2.0}$ |  | V |
| $V_{\text {OL }}$ Logical "0" Output Voltage | $V_{\text {IN }}=0 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=400 \mu \mathrm{~A}$ | DS1630 |  | 0.75 | 1 | V |
|  |  | DS3630 |  | 0.75 | 0.9 | V |
|  | $\mathrm{V}_{\text {IN }}=0 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=16 \mathrm{~mA}$ | DS1630 |  | 0.95 | 1.3 | V |
|  |  | DS3630 |  | 0.95 | 1.3 | V |
|  | $\mathrm{V}_{\text {IN }}=0.4 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=16 \mathrm{~mA}$ | DS1630 |  | 1.2 | 1.6 | V |
|  |  | DS3630 |  | 1.2 | 1.5 | V |

AC Electrical Characteristics $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise specified.

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {pdo }}$ Propagation Delay to a Logical "0" | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 30 | 45 | ns |
|  | $\mathrm{C}_{\mathrm{L}}=250 \mathrm{pF}$ |  | 40 | 60 | ns |
|  | $\mathrm{C}_{\mathrm{L}}=500 \mathrm{pF}$ | 50 | 75 | ns |  |
|  | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 15 | 25 | ns |
|  | $\mathrm{C}_{\mathrm{L}}=250 \mathrm{pF}$ |  | 35 | 50 | ns |
|  | $\mathrm{C}_{\mathrm{L}}=500 \mathrm{pF}$ |  | 50 | 75 | ns |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Unless otherwise specified $\mathrm{min} / \mathrm{max}$ limits apply across the $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ temperature range for the DS 1630 and across the $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ range for the DS3630. All typicals are given for $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ and $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
Note 3: All currents into device pins shown as positive, out of device pins as negative, all voltages referenced to ground unless otherwise noted. All values shown as max or min on absolute value basis.

## Typical Performance Characteristics



## AC Test Circuit and Switching Time Waveforms



Pulse Generator characteristics: $P R R=1.0 \mathrm{MHz}, P W=500 \mathrm{~ns}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}<10 \mathrm{~ns}$, $V_{I N}=0$ to $V_{C C}$

## DS1631/DS3631, DS1632/DS3632, DS1633/DS3633, DS1634/DS3634 CMOS Dual Peripheral Drivers

## General Description

The DS1631 series of dual peripheral drivers was designed to be a universal set of interface components for CMOS circuits.

Each circuit has CMOS-compatible inputs with thresholds that track as a function of $\mathrm{V}_{\mathrm{CC}}$ (approximately $1 / 2 \mathrm{~V}_{\mathrm{CC}}$ ). The inputs are PNPs providing the high impedance necessary for interfacing with CMOS.

Outputs have high voltage capability, minimum breakdown voltage is 56 V at $250 \mu \mathrm{~A}$.

The outputs are Darlington connected transistors. This allows high current operation ( 300 mA max.) at low internal $V_{C C}$ current levels since base drive for the output transistor is obtained from the load in proportion to the required loading conditions. This is essential in order to minimize loading on the CMOS logic supply.

Typical $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ power is 28 mW with both outputs $\mathrm{ON} . \mathrm{V}_{\mathrm{CC}}$ operating range is 4.5 V to 15 V .

The circuit also features output transistor protection if the $\mathrm{V}_{\mathrm{CC}}$ supply is lost by forcing the output into the high
impedance OFF state with the same breakdown levels as when $V_{C C}$ was implied.
Pin-outs are the same as the respective logic functions found in the following popular series of circuits: DS75451, DS75461, DS3611. This feature allows direct conversion of present systems to the DM74C CMOS family and DS1631 series circuits with great power savings.

The DS1631 series is also TTL/DTL compatible at $V_{C C}=5.0 \mathrm{~V}$.

## Features

- CMOS compatible inputs

TTLDTL compatible inputs

- High impedance inputs
- High output voltage breakdown

匈 High output current capability
PNP's
56 V min.
, Same pin-outs and logic functions as DS75451, DS75461, and DS3611 series circuits
m Low $\mathrm{V}_{\mathrm{CC}}$ power dissipation ( 28 mW both outputs "ON" at 5.0 V )


SEE CONNECTION DIAGRAMS FOR ORDERING INFORMATION

Absolute Maximum Ratings (Note 1)

Supply Voltage
Voltage at Inputs Output Voltage Storage Temperature Range Lead Temperature (Soldering, 10 seconds)
${ }^{-} 0.3 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V}$
56 V
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$

|  | MIN | MAX | UNITS |
| :--- | :--- | :---: | :---: |
| Supply Voltage, $\mathrm{V}_{\mathrm{CC}}$ <br> DS1631/DS1632/ | 4.5 | 15 | V |
| DS1633/DS1634 |  |  |  |

Electrical Characteristics (Notes 2 and 3 )

|  | PARAMETER | CONDITIONS |  |  | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| All Circuits |  |  |  |  |  |  |  |  |
|  | Logical "1" Input Voltage | (Figure 1) | $V_{c c}=5 \mathrm{~V}$ |  | 3.5 | 2.5 |  | V |
|  |  |  | $\mathrm{V}_{C C}=10 \mathrm{~V}$ |  | 8.0 | 5 |  | V |
|  |  |  | $V_{c c}=15 \mathrm{~V}$ |  | 12.5 | 7.5 |  | V |
| $V_{\text {IL }}$ | Logical "0" Input Voltage | (Figure 1) | $V_{C C}=5 \mathrm{~V}$ |  |  | 2.5 | 1.5 | V |
|  |  |  | $\mathrm{V}_{C C}=10 \mathrm{~V}$ |  |  | 5.5 | 2.0 | V |
|  |  |  | $\mathrm{V}_{\mathrm{Cc}}=15 \mathrm{~V}$ |  |  | 7.5 | 2.5 | V |
| $\mathrm{I}_{1 \mathrm{H}}$ | Logical "1" Input Current | $\mathrm{V}_{C C}=15 \mathrm{~V}, \mathrm{~V}_{1 \mathrm{~N}}=15 \mathrm{~V}$, (Figure 2) |  |  |  | 0.1 |  | $\mu \mathrm{A}$ |
|  | Logical " 0 " Input Current | $\mathrm{V}_{\text {IN }}=0.4 \mathrm{~V}$, (Figure 3) | $V_{C C}=5 \mathrm{~V}$ |  |  | -50 |  | $\mu \mathrm{A}$ |
|  |  |  | $\mathrm{V}_{\mathrm{cc}}=15 \mathrm{~V}$ |  |  | -200 |  | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Breakdown Voltage | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=250 \mu \mathrm{~A}$, (Figure 1) |  |  | 56 | 65 |  | $V$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Output Low Voltage | $\mathrm{V}_{\mathrm{CC}}=$ Min, (Figure 1) | $\mathrm{I}_{\text {OL }}=100 \mathrm{~mA}$ |  |  | 0.9 |  | V |
|  |  |  | $\mathrm{I}_{\mathrm{OL}}=300 \mathrm{~mA}$ |  |  | 1.1 |  | V |
| DS1631/DS3631 |  |  |  |  |  |  |  |  |
| ${ }^{\text {cco }}$ (0) | Supply Currents | $\mathrm{V}_{\text {IN }}=0 \mathrm{~V}$, (Figure 4) | $V_{C C}=5 \mathrm{~V}$ | Output Low Both Drivers |  | 7 |  | mA |
|  |  |  | $V_{\text {cc }}=15 \mathrm{~V}$ |  |  | 14 |  | mA |
| ${ }^{\text {cce(1) }}$ |  | (Figure 4) | $\mathrm{V}_{\text {CC }}=5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=5 \mathrm{~V}$ | Output High Both Drivers |  | 2 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ Both Drivers |  |  | 7.5 |  | mA |
| $t_{p d 1}$ | Propagation to "1" |  | $V_{C C}=5.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{~V}_{\mathrm{L}}=10 \mathrm{~V}$ <br> (Figure 5) |  |  |  | 200 |  | ns |
| $\mathrm{t}_{\mathrm{pdO}}$ | Propagation to "0" | $V_{C C}=5.0 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{~V}_{\mathrm{L}}=10 \mathrm{~V},$ <br> (Figure 5) |  |  |  | 150 |  | ns |
| DS1632/DS3632 |  |  |  |  |  |  |  |  |
| $\mathrm{I}_{\mathrm{Cc}(0)}$ | Supply Currents | (Figure 4) | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=5 \mathrm{~V}$ | Output Low |  | 8 |  | mA |
|  |  |  | $\mathrm{V}_{\text {CC }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  |  | 18 |  | mA |
| $\mathrm{I}_{\mathrm{CC}(1)}$ |  | $\mathrm{V}_{\text {IN }}=0 \mathrm{~V}$, (Figure 4) | $V_{c c}=5 \mathrm{~V}$ | Output High |  | 2.5 |  | mA |
|  |  |  | $V_{c c}=15 \mathrm{~V}$ |  |  | 9 |  | mA |
| $t_{\text {pd }}$ | Propagation to " 1 " - | $V_{C C}=5.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{~V}_{\mathrm{L}}=10 \mathrm{~V}$ <br> (Figure 5) |  |  |  | 150 |  | ns |
| $\mathrm{t}_{\text {pdo }}$ | Propagation to " 0 " | $V_{C C}=5.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{~V}_{\mathrm{L}}=10 \mathrm{~V},$ <br> (Figure 5) |  |  |  | 150 |  | ns |
| DS1633/DS3633 |  |  |  |  |  |  |  |  |
| $I_{\text {cco }}(0)$ | Supply Currents | $\mathrm{V}_{1 \mathrm{~N}}=0 \mathrm{~V}$, (Figure 4) | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ | Output Low |  | 7.5 |  | mA |
|  |  |  | $V_{C c}=15 \mathrm{~V}$ |  |  | 16 |  | mA |
| $\mathrm{I}_{\mathrm{CC}(1)}$ | , | (Figure 4) | $\mathrm{V}_{\text {CC }}=5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=5 \mathrm{~V}$ | Output High |  | 2 |  | mA |
|  |  |  | $V_{\text {CC }}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  |  | 7.2 |  | mA |
| $t_{\text {pd1 }}$ | Propagation to "1" | $V_{C C}=5.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{~V}_{\mathrm{L}}=10 \mathrm{~V},$ <br> (Figure 5) |  |  |  | 200 |  | ns |
| $\mathrm{t}_{\text {paó }}$ | Propagation to. ' 0 " | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \dot{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{~V}_{\mathrm{L}}=10 \mathrm{~V},$ <br> (Figure 5) |  |  |  | 150 |  | ns |

Electrical Characteristics (Cont'd.)

| PARAMETER | CONDITIONS |  |  | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DS1634/DS3634 |  |  |  |  |  |  |  |
| Supply Currents | (Figure 4) | $V_{C C}=5 \mathrm{~V}, V_{\text {IN }}=5 \mathrm{~V}$ | Output Low |  | 7.5 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=15 \mathrm{~V}$ |  |  | 18 |  | mA |
| ${ }^{\text {I CCO }}$ (1) | $\mathrm{V}_{\text {IN }}=0 \mathrm{~V}$, (Figure 4) | $V_{C C}=5 \mathrm{~V}$ | Output High |  | 3 |  | mA |
|  |  | $\mathrm{V}_{\mathrm{Cc}}=15 \mathrm{~V}$ |  |  | 11 |  | mA |
| $t_{\text {pd1 } 1}$ Propagation to " 1 " | $V_{C C}=5.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{~V}_{\mathrm{L}}=10 \mathrm{~V},$ <br> (Figure 5) |  |  |  | 150 |  | ns |
| $\mathrm{t}_{\text {pao }} \quad$ Propagation to " 0 " | $V_{C C}=5.0 \mathrm{~V}, \mathrm{~T}_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{~V}_{\mathrm{L}}=10 \mathrm{~V},$ <br> (Figure 5 ) |  |  |  | 150 |  | ns |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Unless otherwise specified min/max limits apply across the $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ temperature range for the DS1631, DS1632, DS1633 and DS1634 and across the $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ range for the DS3631, DS3632, DS3633 and DS3634. All typical values are for $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
Note 3: All currents into device pins shown as positive, out of device pins as negative, all voltages referenced to ground unless otherwise noted. All values shown as max or min on absolute value basis.

## Test Circuits



| CIRCUIT | INPUT UNDER TEST | OTHER INPUT | OUTPUT |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  |  | APPLY | MEASURE |
| LM3611 | $\begin{aligned} & V_{I H} \\ & V_{I L} \end{aligned}$ | $\begin{aligned} & V_{1 H} \\ & V_{c \mathrm{cc}} \end{aligned}$ | $\mathrm{IOH}_{\mathrm{O}}$ Iol | $\begin{aligned} & \mathrm{V}_{\mathrm{OH}} \\ & \mathrm{~V}_{\mathrm{OL}} \end{aligned}$ |
| LM3612 | $\begin{aligned} & V_{I H} \\ & V_{I L} \end{aligned}$ | $\begin{aligned} & V_{1 H} \\ & V_{c \mathrm{cc}} \end{aligned}$ | $\begin{aligned} & \mathrm{IOL} \\ & \mathrm{IOH}^{2} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{OL}} \\ & \mathrm{~V}_{\mathrm{OH}} \end{aligned}$ |
| LM3613 | $\begin{aligned} & V_{I H} \\ & V_{I L} \end{aligned}$ | $\begin{aligned} & \text { GND } \\ & V_{I L} \end{aligned}$ | IOH IOL | $\begin{aligned} & \mathrm{V}_{\mathrm{OH}} \\ & \mathrm{~V}_{\mathrm{OL}} \end{aligned}$ |
| LM3614 | $\begin{aligned} & V_{I H} \\ & V_{I L} \end{aligned}$ | $\begin{aligned} & \text { GND } \\ & V_{\text {IL }} \end{aligned}$ | $\begin{aligned} & \mathrm{IOL} \\ & \mathrm{IOH}_{\mathrm{OH}} \end{aligned}$ | $V_{\text {OL }}$ <br> $\mathrm{V}_{\mathrm{OH}}$ |

Note: Each input is tested separately.
FIGURE 1. $\mathrm{V}_{\mathrm{IH}}, \mathrm{V}_{\mathrm{IL}}, \mathrm{V}_{\mathrm{OH}}, \mathrm{V}_{\mathrm{OL}}$

figure 2. I/H


Note A: Each input is tested separately.
Note B: When testing DS1633 and DS1634 input not under test is grounded. For all other circuits it is at $\mathrm{V}_{\mathrm{CC}}$.

FIGURE 3. IIL
FIGURE 4. ICC


Note 1: The pulse generator has the following characteristics: $P R R=500 \mathrm{kHz}, \mathrm{Z}_{\mathrm{OUT}} \approx 50 \mathrm{~s} 2$. Note 2: $\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance.

Connection Diagrams, Truth Tables, and Ordering Information

DS1631
Metal Can Package

(Pin 4 is electrically connected to the case)
Order Number DS1631H/DS3631H

Dual-In-Line Package


TOP VIEW
Order Number 3631N

Dual-In-Line Package


Order Number DS1631J/DS3631J

| Positive logic: $\mathrm{AB}=\mathrm{X}$ |  |  |
| :---: | :---: | :---: |
| A | B | OUTPUT $X$ |
| 0 | 0 | 0 |
| 1 | 0 | 0 |
| 0 | 1 | 0 |
| 1 | 1 | 1 |

DS1632
Metal Can Package

(Pin 4 is electrically connected to the case.)
Order Number DS1632H/DS3632H


Order Number DS1632J/DS3632J
Positive logıc: $\overline{\mathrm{AB}}=\mathrm{x}$

| $\mathbf{A}$ | $\mathbf{B}$ | OUTPUT X |
| :---: | :---: | :---: |
| 0 | 0 | 1 |
| 1 | 0 | 1 |
| 0 | 1 | 1 |
| 1 | 1 | 0 |

## Connection Diagrams, Truth Tables, and Ordering Information

DS 1633
Metal Can Package

(Pin 4 is electrically connected to the case.)
Order Number DS1633H/DS3633H

Positive logic: $\mathrm{A}+\mathrm{B}=\mathrm{X}$

| A | B | OUTPUT X |
| :---: | :---: | :---: |
| 0 | 0 | 0 |
| 1 | 0 | 1 |
| 0 | 1 | 1 |
| 1 | 1 | 1 |

DS1634
Metal Can Package

(Pin 4 is electrically connected to the case.)
Order Number DS1634H/DS3634H


TOP VIEW
Order Number DS3634N

Dual-In-Line Package

Positive logic: $\overline{A+B}=X$

| A | B | OUTPUT.X |
| :---: | :---: | :---: |
| 0 | 0 | 1 |
| 1 | 0 | 0 |
| 0 | 1 | 0 |
| 1 | 1 | 0 |

## General Description

The DS1686/DS3686 is a high voltage/current positive voltage relay driver having many features not available in present relay drivers.

PNP inputs provide both TTL/DTL compatibility and high input impedance for low input loading.

Output leakage is specified over temperature at an output voltage of 54 V . Minimum output breakdown (AC/latch breakdown) is specified over temperature at 5 mA . This clearly defines the actual breakdown of the device since the circuit has incorporated in it an internal reference which does not allow output breakdown latching found in existing relay drivers. Additionally, this internal reference circuit feature will eliminate the need in most cases of an external clamping (inductive transient voltage protection) diode. When the output is turned "OFF" by input logic conditions the resulting inductive voltage transient seen at the output is detected by an internal zener reference. The reference then momentarily activates the output transistor long enough so that the relay energy is discharged. This feature eliminates the need of external circuit protection components and insures output transistor protection.

The outputs are Darlington connected transistors, which allow high current operation at low internal $\mathrm{V}_{\mathrm{CC}}$ current levels-base drive for the output transistor is obtained from the load in proportion to the required loading conditions. Typical $\mathrm{V}_{\mathrm{CC}}$ power with both outputs "ON" is 90 mW .

The circuit also features output transistor protection if the $V_{C C}$ supply is lost by forcing the output into the high impedance "OFF" state with the same breakdown levels as when $V_{C C}$ was applied.

## Features

- TTL/DTL/CMOS compatible inputs
- High impedance inputs (PNP's)
- High output voltage breakdown ( 65 V typ.)
- High output current capability ( 300 mA max.)
- Internal protection circuit eliminates need for output protection diode in most applications
- Output beakdown protection if $V_{C C}$ supply is lost
- Low $V_{C C}$ power dissipation [ 90 mW (typ.) both outputs "ON"]
■ Voltage and current levels compatible for use in telephone relay applications


## Connection Diagrams



Pin 4 is in electrical contact with the case
Order Number DS1686H or DS3686H

Dual-In-Line Package


Order Number DS3686N


TOP VIEW
Order Number DS1686J or DS3686J

Schematic Diagram


Truth Table
Positive logıc: $\overline{\mathrm{AB}}=\mathrm{X}$

| A | B | OUTPUT X |
| :---: | :---: | :---: |
| 0 | 0 | 1 |
| 1 | 0 | 1 |
| 0 | 1 | 1 |
| 1 | 1 | 0 |

Logic "0' output "ON"
Logic " 1 " output "OFF"

## Absolute Maximum Ratings (Note 1)

## Operating Conditions

|  |  |  | MIN | MAX | UNITS |
| :--- | ---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage | $7 V$ | Supply Voltage, $V_{C C}$ |  |  |  |
| Input Voltage | 15 V | DS1686 | 4.5 | 5.5 | $V$ |
| Output Voltage | 56 V | DS3686 | 4.75 | 5.25 | V |
| Storage Temperature Range | 65 C to $+150^{\circ \prime \mathrm{C}}$ | Temperature, $\mathrm{T}_{\mathrm{A}}$ |  |  |  |
| Lead Temperature (Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ | DS1686 | -55 | +125 | ${ }^{\circ} \mathrm{C}$ |
|  |  | DS3686 | 0 | +70 | ${ }^{\circ} \mathrm{C}$ |

Electrical Characteristics (Notes 2 and 3)

| PARAMETER |  | CONDITIONS |  |  | MIN | TYP | MAX | $\frac{\text { UNITS }}{V}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {IH }}$ | Logical '1' Input Voltage |  |  |  | 2.0 |  |  |  |
| IIH | Logical "1" Input Current | $\mathrm{V}_{\mathrm{CC}}=\mathrm{Max}, \mathrm{V}_{\text {IN }}=5.5 \mathrm{~V}$ |  |  |  | 0.01 | 40 | $\mu \mathrm{A}$ |
| VIL | Logical " 0 " Input Voltage |  |  |  |  |  | 0.8 | V |
| 1 IL | Logical " 0 " Input Curtent | $V_{C C}=M a x, V_{\text {IN }}=0.4 \mathrm{~V}$ |  |  |  | -60 | -250 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{CD}}$ | Invut Clamp Voltage | $\mathrm{V}_{C C}=5 \mathrm{~V}, \mathrm{I}_{\text {CLAMP }}=-12 \mathrm{~mA}, \mathrm{~T}=25^{\circ} \mathrm{C}$ |  |  |  | -1.0 | -1.5 | V |
| VOH | Output Breakdown | $V_{\text {CC }}=$ Max, $V_{\text {IN }}=0 \mathrm{~V}, \mathrm{IOUT}^{\text {a }}=5 \mathrm{~mA}$ |  |  | 56 | 65 |  | V |
| $\mathrm{I}^{\mathrm{OH}}$ | Output Leakage | $\mathrm{V}_{\mathrm{CC}}=\mathrm{Max}, \mathrm{V}_{\text {IN }}=0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=54 \mathrm{~V}$ |  |  |  | 0.5 | 250 | $\mu \mathrm{A}$ |
| VOL | Output "ON" Voltage | $\begin{aligned} & V_{C C}=M \ln , \\ & V_{I N}=2 V \end{aligned}$ | ${ }^{\text {I }}$ OUT $=100 \mu \mathrm{~A}$ | DS1686 |  | 0.85 | 1.1 | V |
|  |  |  |  | DS3686 |  | 0.85 | 1.0 | V |
|  |  |  | ${ }^{\prime}$ OUT $=300 \mu \mathrm{~A}$ | DS1686 |  | 0.95 | 1.3 | V |
|  |  |  |  | DS3686 |  | 0.95 | 1.2 | V |
| ICC(1) | Supply Current (Both Drivers) | $V_{\text {CC }}=$ Max, $V_{\text {IN }}=0 \mathrm{~V}$, Outputs Open |  |  |  | 2.0 | 4.0 | mA |
| $\operatorname{ICC}(0)$ | Supply Current (Both Drivers) | $V_{C C}=$ Max, $V_{\text {IN }}=3 \mathrm{~V}$, Outputs Open |  |  |  | 18.0 | 28 | mA |
| ${ }^{\text {tpd0 }}$ | Propagation Delay to a Logical " 0 " (Output Turn "ON") | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{~V}_{\mathrm{L}}=10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \end{aligned}$ |  |  |  | 50 |  | ns |
| tpd 1 | Propagation Delay to a Logical " 1 " (Output Turn "OFF") | $\begin{aligned} & C_{L}=15 \mathrm{pF}, \mathrm{~V}_{\mathrm{L}}=10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \end{aligned}$ |  |  |  | 1.0 |  | $\mu \mathrm{s}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Unless otherwise specified $\mathrm{min} / \mathrm{max}$ limits apply across the $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ temperature range for the DS 1686 and across the $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ range for the DS3686. All typicals are given for $\mathrm{V}_{\mathrm{C}}=5.0 \mathrm{~V}$ and $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
Note 3: All currents into device pins shown as positive, out of device pins as negative, all voltages referenced to ground unless otherwise noted. All values shown as max or $\min$ on absolute value basis.

## AC Test Circuit and Switching Time Waveforms



Note 1: The pulse generator has the following characteristics: PRR $=1 \mathrm{MHz}, 50 \%$ duty cycle, $Z_{\text {OUT }} \geq 50 \Omega, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}} \leq 10 \mathrm{~ns}$.
Note 2: $C_{L}$ includes probe and jig capacitance.


# DS1687IDS3687 Negative Voltage Relay Driver 

## General Description

The DS1687/DS3687 is a high voltage/current negative voltage relay driver having many features not available in present relay drivers.

PNP inputs provide both TTL/DTL compatibility and high input impedance for low input loading.

Output leakage is specified over temperature at an output voltage of -54 V . Minimum output breakdown (AC/ latch breakdown) is specified over temperature at -5 mA . This clearly defines the actual breakdown of the device, since the circuit has incorporated in it an internal reference which does not allow output breakdown latching found in existing relay drivers. Additionally, this internal reference circuit feature will eliminate the need in most cases of an external clamping (inductive transient voltage protection) diode. When the output is turned "OFF", by input logic conditions, the resulting inductive voltage transient seen at the output is detected by an internal zener reference. The reference then momentarily activates the output transistor long enough so that the relay energy is discharged. This feature eliminates the need of external circuit protection components and insures output transistor protection.

The outputs are Darlington connected transistors, which allow high current operation at low internal $V_{c c}$ current levels - base drive for the output transistor is obtained from the load in proportion to the required loading conditions. Typical $V_{C C}$ power with both outputs "ON" is 90 mW .

The circuit also features output transistor protection if the $\mathrm{V}_{\mathrm{CC}}$ supply is lost by forcing the output into the high impedance "OFF" state with the same breakdown levels as when $V_{C C}$ was applied.

## Features

- TTLIDTL/CMOS compatible inputs
n High impedance inputs (PNP's)
田 High output voltage breakdown (-65V typ.)
■ High output current capability ( 300 mA max.)
[0. Internal protection circuit eliminates need for output protection diode in most applications
田 Output breakdown protection if $\mathrm{V}_{\mathrm{CC}}$ supply is lost
(0. Low power dissipation [ 90 mW (typ.) both outputs "ON"]
- Voltage and current levels compatible for use in telephone relay applications


## Connection Diagrams



Pin 4 is in electrical contact with the case
Order Number DS1687H or DS3687H


TOP VIEW
Order Number DS3687N


Order Number DS1687J
or DS3687J

Schematic Diagram


Truth Table

| Posıtive logıc. $\overline{A B}=X$ |
| :--- |
| A |
| B | OUTPUTX | 0 | 0 |
| :---: | :---: |
| 1 | 0 |
| 0 | 1 |
| 1 | 1 |

Logic " 0 " output "ON'
Logic " 1 " output "OFF"

## Operating Conditions

| Supply Voltage | 7 V |
| :--- | ---: |
| Input Voltage | 15 V |
| Output Voltage | -56 V |
| Storage Temperature Range | $-65^{\prime \prime} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Lead Temperature (Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ |


|  | MIN | MAX | UNITS |
| :--- | :---: | :---: | :---: |
| Supply Voltage, $V_{\text {CC }}$ |  |  |  |
| DS1687 | 4.5 | 5.5 | $V$ |
| DS3687 | 4.75 | 5.25 | V |
| Temperature, TA |  |  |  |
| DS1687 | -55 | +125 | ${ }^{\circ} \mathrm{C}$ |
| DS3687 | 0 | +70 | ${ }^{\circ} \mathrm{C}$ |

Electrical Characteristics (Notes 2 and 3)

| PARAMETER |  | CONDITIONS |  |  | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{1} \mathrm{H}$ | Logıcal "1" Input Voltage |  |  |  | 2.0 |  |  | V |
| IIH | Logical " 1 " Input Current | $V_{C C}=M a x, V_{\text {IN }}=5.5 \mathrm{~V}$ |  |  |  | 0.01 | 40 | $\mu \mathrm{A}$ |
| $V_{\text {IL }}$ | Logical "0" Input Voltage |  |  |  |  |  | 0.8 | V |
| IIL | Logical "0" Input Current | $V_{C C}=M a x, V_{I N}=0.4 V$ |  |  |  | -60 | -250 | $\mu \mathrm{A}$ |
| $V_{C D}$ | Input Clamp Voltage | $\mathrm{V}_{\text {CC }}=5 \mathrm{~V}, \mathrm{I}_{\text {CLAMP }}=-12 \mathrm{~mA}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  |  | -1.0 | -1.5 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Breakdown | $\mathrm{V}_{C C}=\mathrm{Max}, \mathrm{V}_{\text {IN }}=0 \mathrm{~V}, \mathrm{IOUT}=-5 \mathrm{~mA}$ |  |  | -56 | -65 |  | V |
| IOH | Output Leakage | $\mathrm{V}_{\text {CC }}=\mathrm{Max}, \mathrm{V}_{\text {IN }}=0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=-54 \mathrm{~V}$ |  |  |  | -0.5 | -250 | $\mu \mathrm{A}$ |
| VOL | Output "ON" Voltage | $\begin{aligned} & V_{C C}=M ı n, \\ & V_{I N}=2 V \end{aligned}$ | IOUT $=100 \mathrm{~mA}$ | DS1687 |  | -0.85 | -1.1 | V |
|  |  |  |  | DS3687 |  | -0.85 | -1.0 | V |
|  |  |  | IOUT $=300 \mathrm{~mA}$ | DS1687 |  | -0.95 | -1.3 | V |
|  |  |  |  | DS3687 |  | -0.95 | -1.2 | V |
| $1 \mathrm{CC}(1)$ | Supply Current (Both Drivers) | $V_{C C}=M a x, V_{I N}=0 V$, Outputs Open |  |  |  | 2.0 | 4.0 | mA |
| ICC(0) | Supply Current (Both Drivers) | $V_{C C}=M a x, V_{I N}=3 V$, Outputs Open |  |  |  | 18.0 | 28 | mA |
| $t_{\text {tpd }}(\mathrm{ON})$ | Propagation Delay to a Logical " 0 " (Output Turn "ON") | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{~V}_{\mathrm{L}}=-10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \end{aligned}$ |  |  |  | 50 |  | ns |
| tpd(OFF) | Propagation Delay to a Logical "1" (Output Turn "OFF") | $\begin{aligned} & C_{L}=15 \mathrm{pF}, V_{\mathrm{L}}=-10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & T_{A}=25^{\circ} \mathrm{C}, V_{C C}=5.0 \mathrm{~V} \end{aligned}$ |  |  |  | 1.0 |  | $\mu \mathrm{s}$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Unless otherwise specified $\mathrm{min} / \mathrm{max}$ limits apply across the $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ temperature range for the DS 1687 and across the $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ range for the DS3687. All typicals are given for $\mathrm{V}_{\mathrm{C}}=5.0 \mathrm{~V}$ and $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
Note 3: All currents into device pins shown as positive, out of device pins as negative, all voltages referenced to ground unless otherwise noted. All values shown as max or min on absolute value basis.

## AC Test Circuit and Switching Time Waveforms



Note 1: The pulse generator has the following characteristics: PRR $=1 \mathrm{MHz}, 50 \%$ duty cycle, $\mathrm{Z}_{\text {OUT }} \geq 50 \Omega, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}} \leq 10 \mathrm{~ns}$. Note 2: $C_{L}$ includes probe and jig capacitance.


## DS78C20/DS88C20 Dual CMOS Compatible Differential Line Receiver

## General Description

The DS78C20 and DS88C20 are high performance, dual differential, CMOS compatible line receivers for both balanced and unbalanced digital data transmission. The inputs are compatible with EIA and Federal Standards.

Input specifications meet or exceed those of the popular DS7820/DS8820 line receiver, and the pinout is identical.

A response pin is provided for controlling sensitivity to input noise spikes with an external capacitor. Each receiver includes a $180 \Omega$ terminating resistor, which may be used optionally on twisted pair lines. The DS78C20 is specified over a $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ operating temperature range, and the DS 88 C 20 over a $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ range.

## Features

- Full compatibility with EIA Standards RS-232-C, RS-422, and RS-423, and Federal Standards 1020 and 1030
- Input voltage range of $\pm 15 \mathrm{~V}$ (differential or commonmode)
- Separate strobe input for each receiver
- $1 / 2 V_{C C}$ strobe threshold for CMOS compatibility
- 5 k input impedance
- 50 mV input hysteresis
- 200 mV input threshold
- Operation voltage range $=4.5 \mathrm{~V}$ to 15 V


## Connection Diagram

Dual-In-Line and Flat Package


## Typical Application

RS-232-C Application with Hysteresis


For signals which require fail-safe or have slow rise and fall times, use $R_{1}$ and $D_{1}$ as shown above; otherwise the positive input (pin 3 or pin 11) may be connected to ground.

| $\mathrm{V}_{\mathbf{C C}}$ | $\mathrm{R}_{\mathbf{1}} \pm 5 \%$ |
| :---: | :---: |
| 5 V | $4.3 \mathrm{k} \Omega$ |
| 10 V | $15 \mathrm{k} \Omega$ |
| 15 V | $24 \mathrm{k} \Omega$ |



Note 1: (Optional internal termination resistor). a) Capacitor in series with internal line termination resistor; terminates the line and saves termination power. Exact value depends on line length.
b) Pin 1 connected to pin 2; terminates the line.
c) Pin 2 open; no internal line termination.
d) Transmission line may be terminated elsewhere or not at all.
Note 2: Optional to control response time.
Note 3: $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 15 V for the DS78C20. For further information on line drivers and line receivers, refer to application notes AN-22, AN-83 and AN-108.


Absolute Maximum Ratings (Note 1)

Supply Voltage<br>Input Voltage<br>Strobe Voltage<br>Output Sink Current<br>Power Dissipation<br>Storage Temperature Range<br>Lead Temperature (Soldering, 10 seconds)<br>18 V<br>$\pm 25 \mathrm{~V}$<br>18 V<br>50 mA 600 mW $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ $300^{\circ} \mathrm{C}$

## Operating Conditions

|  | MIN | MAX | UNITS |
| :---: | :---: | :---: | :---: |
| Supply Voltage ( $\mathrm{V}_{\mathrm{CC}}$ ) | 4.5 | 15 | V |
| Temperature ( $\mathrm{TA}_{\text {A }}$ ) |  |  |  |
| DS78C20 | -55 | +125 | ${ }^{\circ} \mathrm{C}$ |
| DS88C20 | 0 | +70 | ${ }^{\circ} \mathrm{C}$ |
| Common-Mode Voltage ( $\mathrm{V}_{\mathrm{CM}}$ ) | -15 | +15 | V |
| Differential Input Voltage (V DIFF) |  | $\leq 6$ | V |

## Electrical Characteristics (Notes 2 and 3)

| PARAMETER |  | CONDITIONS |  | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {TH }}$ | Differential Threshold Voltage | $\begin{aligned} & \text { IOUT }=-200 \mu \mathrm{~A}, \\ & \mathrm{~V}_{\text {OUT }} \geq \mathrm{V}_{\mathrm{CC}}-1.2 \mathrm{~V} \end{aligned}$ | $-10 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CM}} \leq 10 \mathrm{~V}$ |  | 0.06 | 0.2 | V |
|  |  |  | $-15 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CM}} \leq 15 \mathrm{~V}$ |  | 0.06 | 0.3 | V |
|  |  | IOUT $=1.6 \mathrm{~mA}, \mathrm{~V}_{\text {OUT }} \leq 0.5 \mathrm{~V}$ | $-10 \mathrm{~V} \leq \mathrm{V}_{\text {CM }} \leq 10 \mathrm{~V}$ |  | -0.08 | -0.2 | V |
|  |  |  | $-15 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CM}} \leq 15 \mathrm{~V}$ |  | -0.08 | -0.3 | V |
| $\mathrm{R}_{\text {IN }}$ | Input Resistance | $-15 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CM}} \leq 15 \mathrm{~V}$ |  |  | 5 |  | k $\Omega$ |
| RT | Line Termination Resistance | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 100 | 180 | 300 | $\Omega$ |
| IIND | Data Input Current (Unterminated) | $\mathrm{V}_{C M}=10 \mathrm{~V}$ |  |  | 2 | 3.1 | mA |
|  |  | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ |  |  | 0 | -0.5 | mA |
|  |  | $\mathrm{V}_{\mathrm{CM}}=-10 \mathrm{~V}$ |  |  | -2 | -3.1 | mA |
| $\mathrm{V}_{\text {THB }}$ | Input Balance | $\begin{aligned} & \text { IOUT }=200 \mu \mathrm{~A}, \mathrm{~V}_{\text {OUT }} \geq \\ & \mathrm{V}_{\text {CC }}-1.2 \mathrm{~V}, \mathrm{R}_{\mathrm{S}}=500 \Omega,(\text { Note } 5) \end{aligned}$ | $-7 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CM}} \leq 7 \mathrm{~V}$ |  | 0.1 | 0.4 | V |
|  |  | $\begin{aligned} & \text { IOUT }=1.6 \mathrm{~mA}, \mathrm{~V} \text { OUT } \leq 0.5 \mathrm{~V}, \\ & \left.\mathrm{R}_{\mathrm{S}}=500 \Omega \text {, (Note } 5\right) \end{aligned}$ | $-7 \mathrm{~V} \leq \mathrm{V}^{\prime} \mathrm{CM} \leq 7 \mathrm{~V}$ |  | -0.1 | -0.4 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | Logical "1" Output Voltage | IOUT $=-200 \mu \mathrm{~A}, \mathrm{~V}_{\text {DIFF }}=1 \mathrm{~V}$ |  | $\mathrm{V}_{\mathrm{CC}}{ }^{-1.2}$ | $\mathrm{V}_{\mathrm{CC}}-0.75$ |  | V |
| VOL | Logical "0" Output Voltage | $\mathrm{I}_{\text {OUT }}=1.6 \mathrm{~mA}, \mathrm{~V}_{\text {DIFF }}=-1 \mathrm{~V}$ |  |  | 0.25 | 0.5 | V |
|  | Power Supply Current | $\begin{aligned} & 15 \mathrm{~V} \leq V_{\mathrm{CM}} \leq-15 \mathrm{~V}, \\ & V_{\text {DIFF }}=-0.5 \mathrm{~V} \text { (Both Receivers) } \end{aligned}$ | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ |  | 8 | 15 | mA |
|  |  |  | $\mathrm{V}_{\text {CC }}=15 \mathrm{~V}$ |  | 15 | 30 | mA |
| $\operatorname{liN}(1)$ | Logical "1" Strobe Input Current | $\mathrm{V}_{\text {STROBE }}=15 \mathrm{~V}, \mathrm{~V}_{\text {DIFF }}=3 \mathrm{~V}$ |  |  | 15 | 100 | $\mu \mathrm{A}$ |
| $\operatorname{IIN}(0)$ | Logical "0" Strobe Input Current | $V_{\text {STROBE }}=0 \mathrm{~V}, \mathrm{~V}_{\text {DIFF }}=-3 \mathrm{~V}$ |  |  | -0.5 | -100 | $\mu \mathrm{A}$ |
| $V_{\text {IH }}$ | Logical " 1 " Strobe Input Voltage | I OUT $=1.6 \mathrm{~mA}, \mathrm{~V}_{\mathrm{OL}} \leq 0.5 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ | 3.5 | 2.5 |  | V |
|  |  |  | $\mathrm{V}_{C C}=10 \mathrm{~V}$ | 8.0 | 5 |  | V |
|  |  |  | $\mathrm{V}_{\text {CC }}=15 \mathrm{~V}$ | 12.5 | 7.5 |  | V |
| $V_{\text {IL }}$ | Logical "0" Strobe Input Voltage | $\begin{aligned} & \mathrm{IOUT}=-200 \mu \mathrm{~A}, \\ & \mathrm{~V}_{\mathrm{OH}}=\mathrm{V}_{\mathrm{CC}}-1.2 \mathrm{~V} \end{aligned}$ | $V_{C C}=5 \mathrm{~V}$ |  | 2.5 | 1.5 | V |
|  |  |  | $\mathrm{V}_{\text {CC }}=10 \mathrm{~V}$ |  | 5.0 | 2.0 | V |
|  |  |  | $\mathrm{V}_{\text {CC }}=15 \mathrm{~V}$ |  | 7.5 | 2.5 | V |
| Ios | Output Short-Circuit Current | $\mathrm{V}_{\text {OUT }}=0 \mathrm{~V}, \mathrm{~V}_{\text {CC }}=15 \mathrm{~V}, \mathrm{~V}_{\text {STROBE }}=0 \mathrm{~V},($ Note 4) |  | -5 | -20 | -40 | mA |

## Switching Characteristics $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| tpd0(D) Differential Input to "0' Output | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 60 | 100 | ns |
| ${ }^{\text {tpd1 }}$ (D) Differential Input to "1" Output | $C_{L}=50 \mathrm{pF}$ |  | 100 | 150 | ns |
| $t_{\text {pdO(S) }}$ Strobe Input to "0, Output | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 30 | 70 | ns |
| ${ }^{\text {tpd }}$ 1(S) Strobe Input to "1" Output | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 100 | 150 | ns |

[^26]

## General Description

The DP7310/8310, DP7311/8311 Octal Latched Peripheral Drivers provide the function of latching eight bits of data with open collector outputs, each driving up to 100 mA DC with an operating voltage range of 30 volts. Both devices are designed for low input currents, high input/output voltages, and feature a power up clear (outputs off) function.

The DP7310/8310 are positive edge latching. Two active low write/enable inputs are available for convenient data bussing without external gating.
The DP7311/8311 are fall through latches. The active low strobe input latches data or allows fall through operation when held at logic " 0 ". The latches are cleared (outputs off) with a logic " 0 " on the clear pin.

## Features

- High current, high voltage open collector outputs
- Low current, high voltage inputs
- All outputs simultaneously sink rated current "DC" with no thermal derating at maximum rated temperature.
- Parallel latching or buffering

■ Separate active low enables for easy data bussing

- Internal "glitch free" power up clear
- $10 \% V_{C C}$ tolerance


## Applications

- High current high voltage drivers
- Relay drivers
- Lamp drivers
- LED drivers
- TRIAC drivers
n Solenoid drivers
- Stepper motor drivers
- Level translators
- Fiber optic LED drivers


## Connection Diagrams

Dual-In-Line Package


Order Number DP7310J, DP8310J DP8310N

Dual-In-Line Package


Order Number DP7311J, DP8311J DP8311N

Absolute Maximum Ratings (Note 1)

| Supply Voltage | 7.0 V |
| :--- | ---: |
| Input Voltage | 35 V |
| Output Voltage | 35 V |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| N Package Power Dissipation @ $70^{\circ} \mathrm{C}$ | 1.3 watts |
| Lead Temperature (soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ |

## Operating Conditions

|  | Min. | Max. | Units |
| :--- | :---: | :---: | :---: |
| Supply Voltage $\left(\mathrm{V}_{\mathrm{CC}}\right)$ | 4.5 | 5.5 | V |
| Temperature |  |  |  |
| $\quad$ DP7310/DP7311 | -55 | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\quad$ DP8310/DP8311 | 0 | +70 | ${ }^{\circ} \mathrm{C}$ |
| Input Voltage |  | 30 | V |
| Output Voltage |  | 30 | V |

DC Electrical Characteristics DP7310/DP8310, DP7311/DP8311 (Notes 2 and 3)

| Parameter |  | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{IH}}$ | Logical "1" Input Voltage | . | 2.0 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Logical "0" Input Voltage |  |  |  | 0.8 | V |
| $\mathrm{V}_{\mathrm{OL}}$ | Logical " 0 " Output Voltage <br> DP7310/DP7311 <br> DP8310/DP8311 | Data outputs latched to logical ' 0 ", $\mathrm{V}_{\mathrm{CC}}=\mathrm{min}$. $\begin{aligned} & \mathrm{I}_{\mathrm{OL}}=75 \mathrm{ma} \\ & \mathrm{I}_{\mathrm{OL}}=100 \mathrm{~mA} \end{aligned}$ |  | 0.35 | $\begin{aligned} & 0.4 \\ & 0.5 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| IOH | Logical " 1 "' Output Current <br> DP7310/DP7311 <br> DP8310/DP8311 | Data outputs latched to logical " 1 ", $\mathrm{V}_{\mathrm{CC}}=\mathrm{min}$. $\begin{aligned} & \mathrm{V}_{\mathrm{OH}}=25 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{OH}}=30 \mathrm{~V} \end{aligned}$ |  | 2.5 | $\begin{aligned} & 500 \\ & 250 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |
| $\mathrm{I}_{\mathrm{H}}$ | Logical "1" Input Current | $\mathrm{V}_{\mathrm{IH}}=2.7 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=$ max. |  | 0.1 | 25 | $\mu \mathrm{A}$ |
| 1 | Input Current at Maximum Input Voltage | $V_{1 N}=30 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=\max$. |  | 1 | 250 | $\mu \mathrm{A}$ |
| IIL | Logical "0" Input Current | $\mathrm{V}_{\text {IN }}=0.4 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=\max$. |  | -215 | -300 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {clamp }}$ | Input Clamp Voltage | $\mathrm{I}_{\mathrm{IN}}=-12 \mathrm{~mA}$ |  | -0.8 | -1.5 | V |
| $\mathrm{I}_{\mathrm{CCO}}$ | Supply Current, Outputs On <br> DP7310 <br> DP8310 <br> DP7311 <br> DP8311 | Data outputs latched to a logical "0". All inputs are at logical "1", $V_{C C}=\max$. |  | $\begin{gathered} 100 \\ 100 \\ 88 \\ 88 \end{gathered}$ | $\begin{aligned} & 125 \\ & 152 \\ & 117 \\ & 125 \end{aligned}$ | mA <br> mA <br> mA <br> mA |
| $\mathrm{I}_{\mathrm{CC1}}$ | Supply Current, Outputs Off <br> DP7310 <br> DP8310 <br> DP7311 <br> DP8311 | Data outputs latched to a logic " 1 ". Other conditions same as Icco. |  | $\begin{aligned} & 40 \\ & 40 \\ & 25 \\ & 25 \end{aligned}$ | $\begin{aligned} & 47 \\ & 57 \\ & 34 \\ & 36 \end{aligned}$ | mA <br> mA <br> mA <br> mA |

AC Electrical Characteristics DP7310/DP8310: $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

| Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :--- | :--- | :---: | :---: | :---: |
| $\mathrm{t}_{\text {pd0 }}$ | High to Low Propagation Delay <br> Write Enable Input to Output | Figure 1 |  |  | ns |
| $\mathrm{t}_{\mathrm{pd} 1}$ | Low to High Propagation Delay <br> Write Enable Input to Output | Figure 1 |  |  | ns |
| $\mathrm{t}_{\mathrm{SETUP}}$ | Minimum Set-Up Time <br> Data In to Write Enable Input | $\mathrm{t}_{\mathrm{HoLD}}=0 \mathrm{~ns}$ <br> Figure 1 |  | 12 | ns |
| $\mathrm{t}_{\mathrm{pWH}}$, <br> $\mathrm{t}_{\mathrm{pWL}}$ | Minimum Write Enable Pulse <br> Width | Figure 1 |  | 20 | ns |
| $\mathrm{t}_{\mathrm{THL}}$ | High to Low Output Transition Time | Figure 1 |  | 16 |  |
| $\mathrm{t}_{\mathrm{TLH}}$ | Low to High Output Transition Time | Figure 1 |  | 38 | ns |
| $\mathrm{C}_{\mathrm{IN}}$ | "N" Package Note 4 |  |  | 5 | 15 |

AC Electrical Characteristics DP7311/DP8311: $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

| Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :--- | :--- | :---: | :---: | :---: |
| $\mathrm{t}_{\text {pd0 }}$ | High to Low Propagation Delay <br> Data In to Output | Figure 2 |  |  | ns |
| $\mathrm{t}_{\text {pd1 }}$ | Low to High Propagation Delay <br> Data In to Output | Figure 2 |  | 70 | ns |
| $\mathrm{t}_{\mathrm{SETUP}}$ | Minimum Set-Up Time <br> Data In to Strobe Input | $\mathrm{t}_{\text {HoLD }}=0 \mathrm{~ns}$ <br> Figure 2 |  | -25 | ns |
| $\mathrm{t}_{\mathrm{pWL}}$ | Minimum Strobe Enable Pulse Width | Figure 2 |  | 45 | ns |
| $\mathrm{t}_{\mathrm{pdC}}$ | Propagation Delay Clear to Data Output | Figure 2 |  | 70 | ns |
| $\mathrm{t}_{\mathrm{pWC}}$ | Minimum Clear Input Pulse Width | Figure 2 |  | 10 |  |
| $\mathrm{t}_{\mathrm{THL}}$ | High to Low Output Transition Time | Figure 2 |  | 16 |  |
| $\mathrm{t}_{\mathrm{TLH}}$ | Low to High Output Transition Time | Figure 2 |  | 38 | ns |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance - Any Input | Note 4 |  | 5 | 15 |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: Unless otherwise specified min./max. limits apply across the $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ temperature range for the DP7310/DP7311 and across the $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ for the DP8310/DP8311. All typical values are for $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$.
Note 3: All currents into device pins shown as positive, out of device pins as negative, all voltages referenced to ground unless otherwise noted.
Note 4: Input capacitance is guaranteed by periodic testing. $\mathrm{f}_{\text {TEST }}=10 \mathrm{KHz}$ at $300 \mathrm{mV}, \mathrm{T}_{\mathrm{A}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$

## Logic Table

| DP7310/DP8310 |  |  |  |
| :---: | :---: | :---: | :---: |
| Write <br> Enable 1 <br> WE $_{1}$ | Write <br> Enable 2 <br> WE $_{2}$ | Data <br> Input <br> DI 1-8 $^{2}$ | Data <br> Output <br> DO $_{1-8}$ |
| 0 | 0 | X | Q |
| 0 | - | 0 | 1 |
| 0 | 0 | 1 | 0 |
| - | 0 | 0 | 1 |
| 0 | 1 | X | 0 |
| 1 | 0 | X | Q |
| 1 | 1 | X | Q |


| DP7311/DP8311 |  |  |  |
| :---: | :---: | :---: | :---: |
| Clear | Strobe <br> CLR | Data <br> Input <br> DI $_{1-8}$ | Data <br> Output <br> DO $_{1-8}$ |
| 1 | 1 | X | Q |
| 1 | 0 | 0 | 1 |
| 1 | 0 | 1 | 0 |
| 0 | X | X | 1 |

X = Don't Care
1 = Outputs Off
$0=$ Outputs On
Q = Pre-existing Output
$\boldsymbol{\sim}=$ Positive Edge Transition

## Block Diagram DP7310/DP8310



Block Diagram DP7311/DP8311


Switching Time Waveforms DP7310/DP8310


Switching Time Waveforms DP7311/DP8311


Switching Time Test Circuits DP7310/DP8310 DP7311/DP8311

${ }^{*} \overline{W E}_{1}=$ OV WHEN THE INPUT $=\overline{W E}_{2}$


PULSE GENERATOR CHARACTERISTICS: $\mathrm{Z}_{0}=50 \Omega, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=5 \mathrm{~ns}$

Figure 1
Figure 2


Eight Output/Four Output Fiber Optic LED Driver


Digital Controlled 256 Level Power Supply from 1.2 Volts to 30 Volts


200 mA Drive for a 4 Phase Bifilar Stepper Motor



Reading the State of the Latched Peripherals


Note 5: Always use good $\mathrm{V}_{\mathrm{CC}}$ bypass and ground techniques to suppress transients caused by peripheral loads.
Note 6: Printed circuit board mounting is required if these devices are operated at maximum rated temperature and current (all outputs on DC).

National Semiconductor

## LM195/LM295/LM395 Ultra Reliable Power Transistors

## General Description

The LM195/LM295/LM395 are fast, monolithic power transistors with complete overload protection. These devices, which act as high gain power transistors, have included on the chip, current limiting, power limiting, and thermal overload protection making them virtually impossible to destroy from any type of overload. In the standard TO-3 transistor power package, the LM195 will deliver load currents in excess of 1.0 A and can switch 40 V in 500 ns .

The inclusion of thermal limiting, a feature not easily available in discrete designs, provides virtually absolute protection against overload. Excessive power dissipation or inadequate heat sinking cause the thermal limiting circuitry to turn off the device preventing excessive heating.

The LM195 offers a significant increase in reliability as well as simplifying power circuitry. In some applications where protection is unusually difficult, such as switching regulators, lamp or solenoid drivers where normal power dissipation is low, the LM195 is especially advantageous.
The LM195 is easy to use and only a few precautions need be observed. Excessive collector to emitter voltage can destroy the LM195 as with any power transistor. When the device is used as an emitter follower with low
source impedance, it is necessary to insert a 5.0 k resistor in series with the base lead to prevent possible emitter follower oscillations. Although the device is usually stable as an emitter follower, the resistor eliminates the possibility of trouble without degrading performance. Finally, since it has good high frequency response, supply bypassing is recommended.

The LM195/LM295/LM395 are available in standard TO-3 power packages and solid Kovar TO-5. The LM195 is rated for operation from $-55^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$, the LM295 from $-25^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$, and the LM 395 from $0^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$.

## Features

m Internal thermal limiting

- Greater than 1.0 A output current
- $3.0 \mu \mathrm{~A}$ typical base current
- 500 ns switching time
- 2.0 V saturation
- Base can be driven up to 40 V without damage
m Directly interfaces with CMOS or TTL


## Simplified Circuit and Connection Diagrams



Simplified Circuit of the LM195



## Absolute Maximum Ratings

Collector to Emitter Voltage LM195, LM295 42V LM395 36V
Collector to Base Voltage LM195, LM295 42V LM395 36V
Base to Emitter Voltage (Forward) LM195, LM295 42V
LM395 36V
Base to Emitter Voltage (Reverse) 20 V
Collector Current
Internally Limited
Power Dissipation
Operating Temperature Range
LM195
LM295
LM395
Storage Temperature Range
Lead Temperature (Soldering, 10 seconds) Internally Limited

$$
\begin{array}{r}
-55^{\circ} \mathrm{C} \text { to }+150^{\circ} \mathrm{C} \\
-25^{\circ} \mathrm{C} \text { to }+150^{\circ} \mathrm{C} \\
0^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \\
-65^{\circ} \mathrm{C} \text { to }+150^{\circ} \mathrm{C} \\
300^{\circ} \mathrm{C}
\end{array}
$$

Electrical Characteristics (Note 1)

| PARAMETER | CONDITIONS | LM195, LM295 |  |  | LM395 |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP | MAX | MIN | TYP | MAX |  |
| Collector-Emittel Operating Voltage | $\mathrm{I}_{0} \leq \mathrm{I}_{\mathrm{C}} \leq \mathrm{I}_{\text {MAX }}$ |  |  | 42 |  |  | 36 | v |
| Base to Emitter Breakdown Voltage | $0<\mathrm{V}_{\text {CE }} \leq \mathrm{V}_{\text {CEMAX }}$ | 42 |  |  | 36 | 60 |  | $v$ |
| Collector Current |  |  |  |  |  |  |  |  |
| TO. 3 | $\mathrm{V}_{\text {CE }}<15 \mathrm{~V}$ | 1.2 | 20 |  | 1.0 | 2.0 |  | A |
| TO. 5 | $\mathrm{V}_{\text {CE }} \leq 7.0 \mathrm{~V}$ | 1.2 | 2.0 |  | 1.0 | 2.0 |  | A |
| TO. 220 | $\mathrm{V}_{\text {CE }} \leq 15 \mathrm{~V}$ |  |  |  | 1.0 | 2.0 |  | A |
| Saturation Voltage | $\mathrm{I}_{\mathrm{c}} \leq 1.0 \mathrm{~A}$ |  | 1.8 | 2.0 |  | 1.8 | 2.2 | $\checkmark$ |
| Base Current | $\begin{aligned} & 0 \leq \mathrm{I}_{\mathrm{C}} \leq \mathrm{I}_{\text {MAX }} \\ & 0 \leq \mathrm{V}_{\mathrm{CE}}<\mathrm{V}_{\text {CEMAX }} \end{aligned}$ |  | 3.0 | 5.0 |  | 3.0 | 10 | $\mu \mathrm{A}$ |
| Quiescent Current | $\begin{aligned} & V_{\mathrm{be}}=0 \\ & 0 \leq \mathrm{V}_{\mathrm{CE}} \leq \mathrm{V}_{\mathrm{CEMAX}} \end{aligned}$ |  | 2.0 | 5.0 |  | 2.0 | 10 | mA |
| Base to Emitter Voltage | $\mathrm{I}_{\mathrm{C}}=1.0 \mathrm{~A}, \mathrm{~T}_{A}=+25^{\circ} \mathrm{C}$ |  | 0.9 |  |  | 0.9 |  | v |
| Swutching Time | $\begin{aligned} & V_{C E}=36 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=36 \Omega 2, \\ & T_{A}=+25^{\circ} \mathrm{C} \end{aligned}$ |  | 500 |  |  | 500 |  | ns |
| Thermal Resistance Junction to | TO. 3 Package |  | 2.3 | 3.0 |  | 2.3 | 3.0 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Case (Note 2) | TO. 5 Package |  | 12 | 15 |  | 12 | 15 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

Note 1: Unless otherwise specified, these specifications apply for $-55^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{j}} \leq+150^{\circ} \mathrm{C}$ for the $\mathrm{LM} 195,-25^{\circ} \mathrm{C} \leq T_{j} \leq+150^{\circ} \mathrm{C}$ for the LM295 and $0^{\circ} \mathrm{C} \leq+125^{\circ} \mathrm{C}$ for the LM395.
Note 2: Without a heat sink, the thermal resistance of the TO-5 package is about $+150^{\circ} \mathrm{C} / \mathrm{W}$, while that of the $\mathrm{TO}-3$ package is $+35^{\circ} \mathrm{C} / \mathrm{W}$.

Typical Performance Characteristics










Typical Performance Characteristics (Cont'd.)




## Schematic Diagram



## Typical Applications


1.0 Amp Voltage Follower

*protects against excessive base drive **needed for stability

Power PNP


Time Delay

1.0 MHz Oscillator

1.0 Amp Lamp Flasher

## Typical Applications (Cont'd.)


1.0 Amp Negative Regulator

1.0 Amp Positive Voltage Regulator


Fast Optically Isolated Switch


Optically Isolated Power Transistor


CMOS or TTL Lamp Interface


Two Terminal Current Limiter

*DRIVE VOLTAGE OV TO $\geq 1.0 \mathrm{~V} \leq 42 \mathrm{~V}$
40V Switch

Typical Applications (Cont'd.)

6.0V Shunt Regulator with Crowbar


Low Level Power Switch

*NEED FOR STABILITY

## Emitter Follower



Two Terminal 100 mA Current Regulator


Power One-Shot


High Input Impedance AC Emitter Follower

Typical Applications (Cont'd.)


## Section 7

High Reliability/Radiation Hardened CMOS Programs 883B/RETS ${ }^{\text {TM }}$ Program

The National Semiconductor 883B/RETS ${ }^{\text {TM }}$ Program was conceived with the intent of offering our customers a standardized, off-the-shelf, integrated circuit fully compliant to the current revision of MIL-STD-883.

The following specification outlines the program qualification, quality conformance and processing requirements. Records and data substantiating the testing as specified herein are controlled and administered through National Semiconductor Quality Assurance and Reliability group (located in Santa Clara, California) and are available for review.

As a complement to this program, the National Quality system is designed to encompass the requirements of MIL-Q-9858 and associated documents.

Tom Griffiths, Director
Quality Assurance and Reliability
National Semiconductor Corporation

### 1.0 Scope

### 1.1 Purpose

This specification establishes the requirements for screening and processing of integrated circuits in accordance with MIL-STD-883, Class B.

### 1.2 Intent

This specification is intended to provide the user with the ability to procure standardized, off-the-shelf integrated circuits manufactured by National Semiconductor Corporation that are fully compliant to MIL-STD-883.

### 2.0 Applicable Documents

The following specifications and standards, of the issue in effect on the date of invitation for bids or request for proposal, form a part of this specification to the extent specified herein.

### 2.1 Specifications

Military

| MIL-M-55565 | Microcircuits, Packaging of <br> General Specification for <br> MIL-M-38510 Micro- |
| :--- | :--- |
|  | circuits |
| MIL-C-45662 | Calibration System Requirements <br> MIL-Q-9858 |
| Quality System Requirements |  |

### 2.2 Standards

Military
MIL-STD-105 Sampling Procedures and Tables
MIL-STD-883 Test Methods and Procedures for Microelectronics

### 2.3 Detail Specifications

The detail specification for a particular 883B/RETS ${ }^{\text {TM }}$ microcircuit is the manufacturer's RETS (Reliability Electrical Test Specification, see Figure 2).

### 3.0 General Requirements

The individual requirements shall be as specified herein and in accordance with the applicable detail specification. The static and dynamic electrical performance requirements and electrical test methods shall be as specified in the detall specification.

### 3.1 Process Conditioning, Testing, Reliability and Quality Assurance Screening

Process conditioning, screening and testing shall be as specified in Section 4.0.

| MIL-STD-883 Q.A. <br> Process Level | Applicable Process <br> Flow Chart | Suffix Level <br> Indicator |
| :---: | :---: | :---: |
| B | Figure 1a | 1883 B |

### 3.1.1 Qualification

The 883B/RETS ${ }^{\top M}$ microcircuits furnished under this specification shall be products which have been produced and tested and have passed the qualification tests specified herein. Successful qualification for a given level results in qualification approval for that level and all lower products assurance levels of that device (reference appendix E MIL-M-38510D).

### 3.1.2 Alternate Qualification

In lieu of meeting the requirements of 3.1.1, the manufacturer may establish qualification by performing an initial, one time qualification test. Qualification testing shall be performed on each generic family supplied. Upon successful completion of the qualification program, the manufacturer shall remain qualified for a period not to exceed 12 months.

### 3.2 Quality Conformance Inspection

The 883B/RETS ${ }^{\text {TM }}$ microcircuits furnished under this specification shall be products which have been produced and tested in conformance with all the provisions of this specification for the applicable level. Devices which have been accepted as conforming to a given product assurance level may be furnished as conforming to any other level for which they meet or exceed the quality conformance requirements.

### 3.3 Marking

### 3.3.1 Marking on Each Device

The following marking shall be placed on each microcircuit:
a) Index point (see 3.3.4)
b) Part number (see 3.3.5)
c) Product assurance level (see 3.3.6)
d) Inspection lot identificatıon code (see 3.3.8)
e) Manufacturer's Identification (see 3.3.9)

### 3.3.2 Marking on Initial Container

All of the marking specified in 3.3.1, except the ındex point, shall appear on the initial protection or wrapping for delivery.

### 3.3.3 Marking Permanence

Marking shall be permanent in nature and remain legible after testing. Damage to marking caused by mechanical fixturing in Group B and C tests shall not be cause for lot rejection.

Class B


INTERIM ELECTRICALS AT $+25^{\circ} \mathrm{C}$ DC PER RETS (AT MANUFACTURER'S OPTION)

BURN-IN TEST
MIL-STD. 883 METHOD 1015 $160^{\circ}$ HRS @ $125^{\circ} \mathrm{C}$


FIGURE 1. MIL-STD-883 Screening


HIGH RELIABILITY CMOS


### 3.3.4 Index Point

The index point indicating the starting point for numbering of leads and/or mechanical orientation of the integrated circuit may be a tab, color dot, or other suitable indicator.

### 3.3.5 Part Number

The part number shall be the manufacturer's generic part number.

### 3.3.6 Product Assurance Level

Integrated circuits shall be marked with a code indicating the product assurance level to which they have been tested and found to conform. The code shall consist of /883 followed by the letter B.

### 3.3.7 Formation of Lots

Microcircuits shall be assembled into inspection lots as required to meet the product assurance inspection and test requirements of this specification. An inspection sublot shall consist of microcircuits of a single type contained on a single detail specification, manufactured on the same production line(s) through final seal by the same product techniques, and to the same device design rules and package with the same material requirements, and within the same period not exceeding 6 weeks.

### 3.3.8 Inspection Lot Identification Code

Integrated circuits shall be marked by a 4 -digit date code indicating the date the lot was submitted for inspection. The firșt 2 numbers in the code shall be the last 2 digits of the number of the year. The third and fourth numbers shall be 2 digits indicating the calendar week of the year. When the number of the week is a single digit, it shall be preceded by a zero. Reading from left to right, the code number shall designate year, year, week, week.

### 3.3.9 Manufacturer's Identification

Integrated circuits shall be marked with the name, logo, or trademark of the manufacturer.

### 4.0 Conditions and Methods of Test

Conditions and methods of test shall be in accordance with Method 5004 of MIL-STD-883 and as specified herein on a $100 \%$ basis. The general requirements of MIL-STD-883 apply as applicable. This section establishes the stress screening tests and quality conformance inspection tests for this program. The purpose of these tests is to assure the quality and reliability of the product to a particular process level commensurate with the product's intended application.

### 4.1 Internal Visual Inspection (Precap)

Internal visual inspection shall be performed per MIL-STD-883, Method 2010, Condition B. Hybrid internal visual shall be performed per Method 2017.

### 4.2 Stabilization Bake

Stabilization bake shall be performed per MIL-STD-883, Method 1008, Condition C. The devices shall be stored for 24 hours minimum at $150^{\circ} \mathrm{C}$ minimum. No end point measurements shall be performed.

### 4.3 Temperature Cycling

Temperature cycling shall be performed per MIL.STD883, Method 1010 , Condition C, 10 cycles, from $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$.

### 4.4 Constant Acceleration

Constant acceleration shall be performed per MIL.STD. 883. Method 2001. Condition $E$, at $30,000 \mathrm{G}$ 's, in Y 1 plane only.

### 4.5 Hermeticity

Hermeticity tests shall be performed per the following:

## Fine Leak Testing

Fine leak testing shall be performed per MIL-STD-883, Method 1014, Condition B. The criterion for rejection will be in accordance with MIL-STD-883.

Gross Leak Testing
Gross leak testing shall be performed per MIL.STD-883, Method 1014, Condition C. The rejection criterion will be per MIL-STD-883.

### 4.6 Interim Electrical Parameters

Interim electrical parameters shall be the $25^{\circ} \mathrm{C}$ DC parameters, specified in the detail specification (RETS). (Interim electrical parameters are performed at the manufacturer's option.)

### 4.7 Burn-In

Burn-in shall be performed per MIL-STD-833, Method 1015, Conditions A, B, C or D on all Class B devices. (Burn-In condition varies with product type.)

The ambient temperature shall be $125^{\circ} \mathrm{C}$.

### 4.8 Final Electrical Parameters

Final electrical parameters shall be as specified in the applicable detail specification (RETS). DC testing shall be performed at $25^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}, 125^{\circ} \mathrm{C}$. AC testing shall be performed at $25^{\circ} \mathrm{C}$. The PDA (Percent Defective Allowable) shall be $10 \%$ maximum and shall only apply to DC measurements at $25^{\prime \prime} \mathrm{C}$.

### 4.9 External Visual Inspection

All 883B/RETS ${ }^{\text {TM }}$ microcircuits shall receive external visual inspection per MIL-STD-883, Method 2009.

### 5.0 Quality Assurance Provisions

### 5.1 Quality Conformance Inspection

Quality conformance inspection shall be in accordance with Tables I, II, III and IV. Inspection lot sampling shall be in accordance with Method 5005 of MIL-STD-883. Inspection lots failing to meet quality conformance inspection for a given product assurance level shall be rejected.

### 5.1.1 Group A Inspection

Group A inspection shall consist of the electrical parameters in the RETS (Reliability Electrical Test Specification). If an inspection lot is made up of a collection of sublots, each sublot shall be subjected to Group $A$, as specified, (see Table 1).

### 5.1.2 Group B Inspection

Group B inspection consists of construction testing. This sample test sequence includes physical dimensions,
resistance to solvents, internal visual and mechanical, bond strength and solderability (see Table II). The Group B qualifies the inspection sublot the sample is pulled from. It also qualifies all generically similar devices if the date code is within 6 weeks of the sample date code.

### 5.1.3 Group C Inspection

Group C inspection consists of die stress testing. This sample test sequence includes operating life, temperature cycling, constant acceleration, hermeticity, visual examination and end point electricals (see Table III). A Group C qualifies the lot the sample is pulled from and all generically similar die types for a period of 90 days.

### 5.1.4 Group D Inspection

Group D testing further stresses the package and the die. The Group D tests include physical dimensions, lead integrity, hermeticity, thermal shock, temperature cycling, moisture resistance, mechanical shock, vibration variable frequency, constant acceleration, salt atmosphere, visual examination, and end point electricals (see Table IV). A Group D qualifies the lot the sample is pulled from and all devices built in the same package for a period of 6 months.

TABLE I. GROUP A ELECTRICAL TEST

| SUBGROUPS | CLASS B |
| :--- | :---: |
| LTPD |  |$|$| Subgroup 1 <br> Static tests at $25^{\circ} \mathrm{C}$ | 7 |
| :--- | :---: |
| Subgroup 2 <br> Static tests at maximum rated <br> operating temperature | 7 |
| Subgroup 3 <br> Static tests at minimum rated <br> operating temperature | 7 |
| Subgroup 4 <br> Dynamic tests at 25 |  |
| Subgroup 5 <br> Dynamic tests at maximum rated <br> operating temperature | 7 |
| Subgroup 6 <br> Dynamic tests at minimum rated <br> operating temperature | 7 |
| Subgroup 7 <br> Functional tests at 25 |  |
| Subgroup 8 <br> Functional tests at maximum and <br> minimum rated operating <br> temperature | 10 |
| Subgroup 9 <br> Switching tests at 25 | $\mathbf{C}$ |


| TABLE IV. GROUP D INSPECTION |  |  |  |
| :--- | :---: | :---: | :---: |
| TEST | METHOD | CONDITIONS | CLASS B <br> LTPD |
| (MAX ACC = 1) |  |  |  |


| TABLE II. GROUP B INSPECTION |  |  |  |
| :---: | :---: | :---: | :---: |
| TEST | METHOD | CONDITIONS | CLASS B |
| Subgroup 1 <br> Physical dimension | 2016 |  | 2 devices <br> (No failures) |
| Subgroup 2 <br> a) Resistance to solvents | 2015 |  | 3 devices <br> (No failures) |
| Subgroup 3 <br> Solderability | 2003 | Soldering temperature of $260 \pm 10^{\circ} \mathrm{C}$ | 15 leads <br> ( 3 units min <br> No failures) |
| Subgroup 4 Internal visual and mechanical | 2014 | Failure criteria from design \& construction requirements of applicable procurement document | 1 device <br> (No failures) |
| Subgroup 5 <br> Bond strength | 2011 | Test condition C or D | 15 Bonds (10 units min No failures) |


| TABLE III. GROUP C InSPECTION |  |  |  |
| :---: | :---: | :---: | :---: |
| TEST | METHOD | CONDITIONS | $\begin{gathered} \text { CLASS B } \\ \text { LTPD } \\ \text { (MAX ACC }=1 \text { ) } \end{gathered}$ |
| Subgroup 1 <br> Operating Life Test <br> End point electricals | 1005 | Test conditions to be specified 1000 hours @ $+125^{\circ} \mathrm{C}$ <br> as specified in the applicable detail specification $\left(+25^{\circ} \mathrm{C}\right)$ | 5 |
| Subgroup 2 <br> Temperature cycling <br> Constant acceleration <br> Seal <br> Fine <br> Gross <br> Visual examination <br> End point electrical <br> parameters | $\begin{aligned} & 1010 \\ & 2001 \\ & 1014 \\ & \\ & 1010 \end{aligned}$ | Test condition C <br> Test condition $\mathrm{E}, \mathrm{Y} \uparrow$ axis <br> As applicable <br> As specified in applicable device specification $\left(+25^{\circ} \mathrm{C}\right)$ | 15 |

883 PROCESS FLOW

| TEST | MIL-STD-883 <br> METHOD | TTL, LS, LOW POWER <br> CMOS, LINEAR, <br> MOS/LSI, MEMORY | HYBRID |  |
| :--- | :--- | :--- | :--- | :---: |
| Internal visual | 2010, Cond. B | $100 \%$ | $100 \%$ (Method 2017) |  |
| Bake | 1008, Cond. C | $100 \%$ | $100 \%$ |  |
| Temperature cycling | 1010, Cond. C | $100 \%$ | $100 \%$ |  |
| Constant acceleration | 2001, Cond. E | $100 \%$ | $100 \%$ |  |
| Fine leak | 1014, Cond. B | $100 \%$ | $100 \%$ |  |
| Gross leak | 1014, Cond. C | $100 \%$ | $100 \%$ |  |
| Burn-in | 1015, Cond. A, B, C or D | $100 \%$ | $100 \%$ |  |
| Electrical test | Per the applicable <br> detail specification |  | $100 \%$ RETS |  |
| Group A | 2009 | $100 \%$ | $100 \%$ |  |
| External visual |  |  |  |  |

### 6.0 DATA

### 6.1 Certificate of Conformance

All 883B/RETS ${ }^{\text {TM }}$ microcircuits shipped shall be accompanied by a Certificate of Conformance as shown on the opposite page.

### 6.2 Attributes Data

Attributes data for $100 \%$ screening will not normally be provided, but shall be retained on file. Copies are available at nominal cost.

### 6.3 Quality Conformance Data

Quality conformance data will not normally be provided, but shall be retained on file. Copies are available at nominal cost.

## 883B/RETS ${ }^{\text {TM }}$ MICROCIRCUITS FROM National Semiconductor Corporation

## CERTIFICATE <br> OF

 CONFORMANCE| TEST | MIL-STD-883 METHOD** | REQUIREMENT |
| :--- | :--- | :---: |
| INTERNAL VISUAL | 2010 B | $100 \%$ |
| STABILIZATION BAKE | 1008 C 24 HRS @ $+150^{\circ} \mathrm{C}$ | $100 \%$ |
| TEMPERATURE CYCLING | $1010 \mathrm{C} 10 \mathrm{CYCLES}-65^{\circ} \mathrm{C} /+150^{\circ} \mathrm{C}$ | $100 \%$ |
| CONSTANT ACCELERATION | 2001 E | $100 \%$ |
| FINE LEAK | $1014 \mathrm{~B} 5 \times 10^{-8}$ | $100 \%$ |
| GROSS LEAK | 1014 C 2 | $100 \%$ |
| BURN-IN | 1015160 HRS @ +125 ${ }^{\circ} \mathrm{C}$ | $100 \%$ |
| FINAL ELECTRICAL | $+25^{\circ} \mathrm{C} \mathrm{DC} \mathrm{PER} \mathrm{NSC} \mathrm{RETS}$ | $100 \%$ |
| PDA | $10 \%$ MAX ALLOWABLE |  |
|  | $+125^{\circ} \mathrm{C}$ DC PER NSC RETS | $100 \%$ |
| QA ACCEPTANCE | $-55^{\circ} \mathrm{C}$ DC PER NSC RETS | $100 \%$ |
| EXTERNAL VISUAL | $+25^{\circ} \mathrm{C}$ AC PER NSC RETS | $100 \%$ |
|  | LTPD SAMPLE |  |
|  | 2009 | $100 \%$ |

* RETS = REL ELECTRICAL TEST SPECIFICATION
** All METHODS TO CURRENT REVISION LEVELS
THIS IS TO CERTIFY THAT ALL 883B/RETS ${ }^{\text {TM }}$ MICROCIRCUITS SUPPLIED TO YOUR PURCHASE ORDER COMPLY WITH ALL THE REQUIREMENTS, SPECIFICATIONS AND DOCUMENTS PERTINENT TO NATIONAL'S 883B/RETS ${ }^{\text {TM }}$ MICROCIRCUIT PROGRAM. ALL TEST DATA AND CERTIFICATION IS ON FILE AT OUR FACILITY.

| Part Number |
| :--- |
| P.O. Number |
| Date Code(s)____ |
| Lot Code(s) |

# 883S/RETSTм PRODUCTS FROM National Semiconductor 

### 1.0 Scope

### 1.1 Purpose

This document establishes the requirements for screening and processing of integrated circuits in accordance with MIL-STD-883, Class S where such devices are not available as M38510 Class $S$ devices. These products shall be referred to as $8835 / R E T S^{\top M}$ microcircuits.

### 1.2 Intent

This program is intended to provide the user with the ability to procure 883 S/RETS ${ }^{\text {TM }}$ microcircuits. These are standardized integrated circuits manufactured and processed by National Semiconductor Corporation in accordance with the requirements of MIL-STD-883, for Class S devices.

### 2.0 Applicable Documents

The following specifications and standards of the issue in effect on the date of invitation for bids or request for proposal, form a part of this specification to the extent specified herein.

### 2.1 Specifications

| Military |  |
| :--- | :--- |
| MIL-M-55565 | Microcircuits, Packaging of |
| MIL-M-38510 | General Specification for |
|  | Microcircuits |
| MIL-C-45662 | Calibration System <br> Requirements |
| MIL-Q-9858 | Quality System Requirements <br> MIL-STD-1331 <br> Microelectronics Terms and <br> Definitions |

### 2.2 Standards

Military
MIL-STD-105 Sampling Procedures and Tables
MIL-STD-883 Test Methods and Prodedure for Microelectronics
MIL-STD-976 Certification Requirements for Microcircuits

### 2.3 Detail Specifications

The detail specification for a particular device is the National Semiconductor RETS (Reliability Electrical Test Specification, see Figure 1). The RETS is a one page translation of the National Semiconductor electrical test programs
used to test 883B/RETS ${ }^{\top M}$ and 883S/RETS ${ }^{\top M}$ microcircuits. For devices available as JM38510, Class S, the detail specification shall be the applicable MIL-M-38510 slash sheet, and all applicable requirements of MIL-M-38510 shall apply.

### 3.0 Requirements

### 3.1 General

The individual requirements shall be as specified herein and in accordance with the applicable detail specification. The static and dynamic electrical performance requirements for the integrated circuits and electrical test methods shall be as specified in the detail specification.

### 3.1.1 Conflicting Requirements

In the event of conflict between the requirements of this specification and other requirements of the applicable device specification, the precedence in which requirements shall govern, in decending order, is as follows:
a) Applicable device specification (detail specification).
b) This specification.
c) Specifications, standards, and other documents referenced in 2.1.

### 3.1.2 Terms, Definitions, and Symbols

For the purpose of this specification, the terms, definitions, and symbols of MIL-STD-883, MIL-STD-1331, and paragraph 3.1.3 of MIL-M-38510 shall apply and shall be used wherever they are pertinent, except as follows:
a) Procuring Activity (see MIL-M-38510, paragraph 3.1.3 (n)) shall be that organization (either OEM manufacturer or government agency) which generates the actual purchase order or contract used to procure material under this specification. For material purchased through a franchised distributor, the procuring activity shall be that organization which places the purchase order or contract with the distributor.
b) The Qualifying Activity (see MIL-M-38510, paragraph 3.1.3 (o)) shall be National's Quality Assurance Department.

HIGH RELIABILITY CMOS



### 3.1.3 Country of Manufacture

All 883S/RETS ${ }^{\text {TM }}$ microcircuits provided under this specification shall be manufactured, assembled and tested within the U.S. and its territories.

### 3.1.4 Line Certification

All 883S/RETS ${ }^{T M}$ microcircuits provided under this specification shall be fabricated and assembled in the United States on lines which have been certified for the fabrication and assembly of JAN microcircuits in accordance with the requirements of MIL-STD-976 and paragraph 3.4.1.2 of MIL-M-38510. (Note: This is not to be interpreted as implying in any way that parts supplied to this specification are JAN qualified devices or are equivalent to JAN qualified devices.)

### 3.2 Product Assurance Requirements

883S/RETS ${ }^{\text {TM }}$ microcircuits shall be those which have been subjected to, and passed all applicable requirements, tests, and inspections detailed herein, including wafer lot acceptance screening, qualification, and quality conformance inspection requirements. Where shown, method references are per MIL-STD-883.

### 3.2.1 Qualification

883S/RETS ${ }^{\text {TM }}$ microcircuits furnished under this specification shall be products which have been produced and tested and have passed the qualification tests specified herein. The required qualification tests shall be Group A, Group B, and Group D testing as specified in Tables I, II, and III of this specification.

### 3.2.2 Screening

All 883S/RETS ${ }^{\text {TM }}$ microcircuits to be delivered in accordance with this specification shall have been subjected to, and passed, all the screening tests detailed in method 5004 of MIL-STD-883 for Class S devices (See Figure 2). Sampling inspections shall not be an acceptable substitute for any specified screening test.

### 3.2.3 Quality Conformance Inspection

Microcircuits shall not be accepted or approved for delivery until the inspection lot has passed quality conformance inspection (See Section 5.1).

### 3.2.4 Wafer Lot Acceptance

883S/RETS ${ }^{\text {TM }}$ microcircuits furnished under this specification shall be products from wafer lots
that are subjected to and successfully meet the wafer lot acceptance inspections and tests specified in Table IV.

### 3.2.5 Traceability

For 883S/RETS ${ }^{T M}$ microcircuits, each delivered microcircuit shall be traceable to the inspection and wafer lots.

### 3.2.6 In Process Verification and Die Attach Lead Bonding

Die attach and bonding operations shall be monitored in accordance with paragraph 4.1.1.2 of MIL-M-38510. Samples will be taken at the beginning of the shift and every two hours thereafter.

### 3.3 Design Documentation

National Semiconductor shall retain on file the design and construction information required by paragraph 3.5.4 of MIL-M-38510.

### 3.4 Internal Conductors

Internal thin film conductors on silicon die (metallization stripes, contact areas, bonding interfaces, etc.) shall meet the requirements of paragraph 3.5.4 of MIL-M-38510.

### 3.5 Lead Material and Finish

Lead material and finish shall be as defined in MIL-M-38510, paragraph 3.5.6.

### 3.6 Glassivation

All 883S/RETS ${ }^{\top M}$ microcircuits shall be glassivated. The minimum glassivation thickness shall be $6,000 \AA$ for $\mathrm{SiO}_{2}$ or $2,000 \AA$ for $\mathrm{Si}_{3} \mathrm{~N}_{4}$. The glassivation/nitridation shall cover all electrical conductors except the bonding pads.

### 3.7 Die Thickness

Unless otherwise specified, the minimum die thickness for all microcircuits shall be 0.006 inch $(0.15 \mathrm{~mm})$.

### 3.8 Marking

### 3.8.1 Marking on Each Device

The following marking shall be placed on each integrated circuit:
a) Index point (see 3.8.4)
b) Part number (see 3.8.5)
c) Product assurance level (see 3.8.6)
d) Inspection lot identification code (see 3.8.8)


Figure 2
883S/RETSTM PRODUCT SCREENING FLOW (PER MLI-STD-883, METHOD 5004 AND MLI-M.38510)
e) National Semiconductor Identification (see 3.8.9)
f) Country of Origin (see 3.8.10)
g) Serial number (see 3.8.11)
h) SEM acceptance lot number (3.8.12)

### 3.8.2 Marking on Initial Container

All of the marking specified in 3.8.1, except the index point, shall appear on the initial protection or wrapping for delivery. The serial number range shall be shown rather than individual serial numbers.

### 3.8.3 Marking Permanence

Marking shall be permanent in nature and remain legible after testing. Damage to marking caused by mechanical fixturing in Group B and $D$ tests shall not be cause for lot rejection.

### 3.8.4 Index Point

The index point indicating the starting point for numbering of leads and/or mechanical orientation of the integrated circuit may be a tab, color dot, or other suitable indicator.

### 3.8.5 Part Number

The part number shall be the National Semiconductor part number.

### 3.8.6 Product Assurance Level

883S/RETS ${ }^{\text {TM }}$ microcircuits shall be marked with a code indicating the product assurance level to which they have been tested and found to conform. The code shall consist of $/ 883$ followed by the letter $S$.

### 3.8.7 Formation of Lots

883S/RETS ${ }^{\top M}$ microcircuits shall be assembled into inspection lots and sublots as required to meet the product assurance inspection and test requirements of this specification. An inspection lot and sublot shall be as defined in MIL-M-38510, paragraphs 3.1.3b and 3.1.3d.


### 3.8.8 Inspection Lot Identification Code

Integrated circuits shall be marked by a 4-digit date code indicating the date the lot was submitted for inspection. The first 2 numbers in the code shall be the last 2 digits of the number of the year. The third and fourth numbers shall be 2 digits indicating the calendar week of the year. When the number of the week is a single digit, it shall be preceded by a zero. When more than one wafer lot is used to assemble an inspection lot, an alpha character will be suffixed to the date code to differentiate between wafer lots and to maintain wafer lot traceability (see paragraph 3.2.5).

### 3.8.9 National Semiconductor Identification

Integrated circuits shall be marked with the Na tional Semiconductor logo (NS or $\approx$ ).

### 3.8.10 Country of Origin

The letters "U.S.A." shall be marked below or adjacent to the other specified markings.

### 3.8.11 Serialization

Prior to the first recorded electrical measurement in screening each 883S/RETS ${ }^{\top M}$ microcircuit shall be marked with a unique serial number assigned consecutively within the inspection lot. This serial number allows traceability of test results to the individual microcircuit within that inspection lot. Inspection lot records shall be maintained to provide traceability from the serial number to the specific wafer lot from which the devices originated.

### 3.8.12 SEM Acceptance Lot Number

Each 883S/RETS ${ }^{\top M}$ microcircuit shall be marked with an identifying number providing traceability to SEM acceptance and wafer lot acceptance data by metallization run number.

### 3.8.13 Marking Location and Sequence

Unless otherwise specified, the part number, inspection lot identification code, and serialization (where applicable), shall be located on the top surface of flat packages or dual-in-line configurations and on either the top or the side of cylindrical packages (TO-99 and similar configurations). The index point shall be marked as specified in appendix C of MIL-M-38510. The balance of the markings may be placed in any suitable location so as to perform their required functions and not interfere with the other markings. Where package size prohibits marking of all information shown in 3.8.1, the order of priority for inclusion shall be $a, b, g, c, e, d, f, h$.

### 4.0 Conditions and Methods of Test

Conditions and methods of test shall be in accordance with Method 5004 of MIL-STD-883 and as specified herein on a $100 \%$ basis. The general requirements of MIL-STD-883 apply as applicable. This section establishes the stress screening tests and test methods for this program. The purpose of these tests is to assure the quality and reliability of the product to a level commensurate with the product's intended application.

### 4.1 Internal Visual Inspection (Precap)

Internal visual inspection shall be performed per MIL-STD-883, Method 2010 Condition A.

### 4.2 Stabilization Bake

Stabilization bake shall be performed per MIL-STD-883, Method 1008, Condition C. The devices shall be stored for 24 hours minimum at $150^{\circ} \mathrm{C}$ minimum.

### 4.3 Temperature Cycling

Temperature cycling shall be performed per MIL-STD-883, Method 1010, Condition C, 10 cycles, from $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$.

### 4.4 Constant Acceleration

Constant acceleration shall be performed per MIL-STD-883, Method 2001, Condition E, at 30,000 G's, in Y1 axis only.

### 4.5 Hermeticity

Hermeticity test shall be performed per the following to determine the seal integrity of the package.

Fine Leak Testing
Fine leak testing shall be performed per MIL-STD-883, Method 1014, Condition B. The rejection criterion shall be per MIL-STD-883.

Gross Leak Testing
Gross leak testing shall be performed per MIL. STD-883, Method 1014, Condition C. The rejection, criteria shall be per MIL-STD-883.

### 4.6 Particle Impact Noise Detection (PIND)

Particle impact noise detection testing shall be performed in accordance with MIL-STD-883, Method 2020 and paragraph 4.6 .3 of MIL. M-38510

### 4.7 Serialization

Each unit shall be serialized (see paragraph 3.8.11).

### 4.8 Interim Electrical Parameters (Pre Burn-In)

Interim electrical parameters shall be the $25^{\circ} \mathrm{C}$ DC parameters, specified in the detail specification (RETS). All parameters for which drift limits ( $\Delta$ 's) are specified on the RETS shall be read-and-recorded. (Note: $\Delta$ parameters are specified for all device types.)

### 4.9 Burn-in

Burn-in shall be performed per MIL-STD-883, Method 1015, Conditions A, B, C or D, at the supplier's discretion. (Burn-in condition varies with product type.) For CMOS devices, the burn-in sequence shall include Static I, Static II, and Dynamic Burn-in (as shown in figure 1).

The ambient temperature shall be $125^{\circ} \mathrm{C}$, and the duration shall be 240 hours minimum. For CMOS devices, the Static I and Static II burn-in shall each be 24 hours in duration.

### 4.10 Interim Electrical Parameters (Post Burn-In)

The measurements defined in paragraph 4.8 shall be repeated. The PDA shall be $5 \%$. For CMOS, the PDA shall be $5 \%$ for the Static I and Static II burn-ins combined and $5 \%$ for the Dynamic Burn-in. Drift limits (see 4.11) will be included in the PDA only for CMOS.

### 4.11 Delta Calculation

Deltas shall be computed for all parameters for which drift limits are established by the RETS. All units failing the drift limits shall be removed from the lot. Drift limit failures shall be included in the PDA (see 4.10) only for CMOS devices.

### 4.12 Hermeticity Testing

Fine and gross leak testing shall be performed as defined in paragraph 4.5.

### 4.13 Final Electrical Parameters

Final electrical parameters shall be as defined in the applicable detail specification. DC testing shall be performed at $25^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$, and $+125^{\circ} \mathrm{C}$ (except that any $25^{\circ} \mathrm{C}$ tests performed in 4.8 need not be repeated), and AC tests shall be performed at $25^{\circ} \mathrm{C}$.

### 4.14 Radiographic Inspection

Radiographic inspection shall be performed in accordance with MIL-STD-883. Method 2012.

### 4.15 Quality Conformance Testing

Samples shall be randomly selected from the lot, and quality conformance inspection shall be performed in accordance with 5.0.

### 4.16 External Visual Inspection

All 883S/RETS ${ }^{\text {TM }}$ microcircuits shall receive external visual inspetion per MIL-STD-883, Method 2009.

### 5.0 Quality Assurance Provisions

### 5.1 Quality Conformance Inspection

Quality conformance inspection shall be in accordance with Tables I, II, and III. Inspection Iot sampling shall be in accordance with Method 5005 of MIL-STD-883. Inspection lots failing to meet quality conformance inspection for the Class $S$ product assurance level shall be rejected.

### 5.1.1 Group A Inspection

Group A inspection shall consist of the electrical parameters in the RETS. If an inspection lot is made up of a collection of sublots, each sublot shall be subjected to Group A (See Table I).

### 5.1.2 Group B Inspection

Group B inspection consists of those tests specified in Table II. Group B tests will be performed on every inspection lot.

### 5.1.3 Group D Inspection

Group D testing consists of those package oriented tests specified in Table III. Group D testing will be performed within National's 883B/RETS ${ }^{\text {TM }}$ program once every 6 months per package type.

### 6.0 Data

### 6.1 Data Shipped with Parts

One copy of the following data shall be provided with each shipment of $883 \mathrm{~S} /$ RETS $^{\text {TM }}$ microcircuits:
a) Attributes and variables data for $100 \%$ screening.
b) A reject list showing, by serial number, all rejected devices and cause for rejection.
c) X-ray report.
d) Certificate of Conformance for water lot acceptance.

### 6.2 Data Retained on File

The following data will be maintained on file at National Semiconductor for 3 years (but may be provided with shipment upon special order).
a) X-ray film (radiographs).
b) SEM photos
c) Attributes and variables data for Quality Conformance testing.

### 7.0 Hybrid Devices

Hybrid devices are not available through the $883 \mathrm{~S} / \mathrm{RETS}^{\text {TM }}$ product program, but modified Class S flows are available on a special order basis.

TABLE1.GROUPAELECTRICALTEST (PER METHOD 5005, TABLE I)

| SUBGROUPS | $\begin{aligned} & \text { CLASS S } \\ & \text { LTPD } \end{aligned}$ |
| :---: | :---: |
| Subgroup 1 <br> Static tests at $25^{\circ} \mathrm{C}$ | 5 |
| Subgroup 2 <br> Static tests at $125^{\circ} \mathrm{C}$ | 7 |
| Subgroup 3 <br> Static tests at $-55^{\circ} \mathrm{C}$ | 7 |
| Subgroup 4 (note 1) Dynamic tests at $25^{\circ} \mathrm{C}$ | 5 |
| Subgroup 5 (note 1) Dynamic tests at $125^{\circ} \mathrm{C}$ | 7 |
| Subgroup 6 (note 1) Dynamic tests at $-55^{\circ} \mathrm{C}$ | 7 |
| $\begin{aligned} & \text { Subgroup }{ }^{7} \text { (note }{ }^{1} \text { ) } \\ & \text { Functional tests at } 25^{\circ} \mathrm{C} \end{aligned}$ | 5 |
| Subgroup 8 (note 1) <br> Functional tests at $125^{\circ} \mathrm{C}$ and $-55^{\circ} \mathrm{C}$ | 10 |
| Subgroup 9 <br> Switching tests at $25^{\circ} \mathrm{C}$ | 7 |
| Subgroup 10 <br> Switching tests at $125^{\circ} \mathrm{C}$ | 10 |
| Subgroup 11 <br> Switching tests at $-55^{\circ} \mathrm{C}$ | 10 |

NOTES:

1. NATIONAL WILL NORMALLY PERFORM these subgroups at the same time AS SUBGROUPS 1, 2, AND 3 RESPECTIVELY.
2. MAXIMUM ACCEPT NUMBER FOR EACH SIJBGROUP SHALL BE 1.

TABLE II. GROUP B INSPECTION (PER METHOD 5005, TABLE IIA)

| TEST | $\left\lvert\, \begin{gathered} \text { MIL_STD-883 } \\ \text { METHOD } \end{gathered}\right.$ | CONDITIONS | CLASS S LTPD OR SAMPLE SIZE |
| :---: | :---: | :---: | :---: |
| Subgroup 1 <br> Physical dimensions Internal Water Vapor Content | $\begin{aligned} & 2016 \\ & 1018 \end{aligned}$ | (note 5) | 2 devices (no failures) 3 devices (no failures) |
| Subgroup 2 (note 1) <br> a) Resistance to solvents <br> b) Visual and mechanical <br> c) Bond strength <br> d) Die shear | $\begin{aligned} & 2015 \\ & 2013 \\ & \text { and } \\ & 2014 \\ & 2011 \\ & 2019 \end{aligned}$ | Failure criteria from design \& construction requirements of applicable procurement document Test condition C or D <br> Per table I of Method 2019 for applicable die size | 3 devices (No failures) <br> 2 devices (no failures) <br> 2 devices all wires (no fallures) <br> 3 devices (no failures) |
| Subgroup 3 <br> Solderability (note 2) | 2003 | Soldering temperature of $260 \pm 10^{\circ} \mathrm{C}$ | LTPD $=15$ <br> 15 leads (3 units min, no failures) |
| Subgroup 4 <br> a) Lead integrity <br> b) Seal (fine and gross) | $\begin{aligned} & 2004 \\ & 1014 \end{aligned}$ | Test condition B2 Cond B or C, As applicable | 2 devices (no failures) |
| Subgroup 5 (note 3) <br> a) Electrical parameters <br> b) Operating life <br> c) Electrical parameters | 1005 | Per applicable RETS ( $25^{\circ}, \mathrm{DC}$ ) Test condition A, B, C or D Per applicable RETS $\left(25^{\circ} \mathrm{C}, \mathrm{DC}\right)$ | $L T P D=5$ <br> 77 devices (one fallure) |
| Subgroup 6 (note 3) <br> a) Electrical parameters <br> b) Temperature cycling <br> c) Constant acceleration <br> d) Seal (fine and gross) <br> e) Electrical parameters | $\begin{aligned} & 1010 \\ & 2001 \\ & 1014 \end{aligned}$ | Per applicable RETS $\left(25^{\circ} \mathrm{C}, \mathrm{DC}\right)$ Test condition $\mathrm{C}, 100$ cycles min. Test condition E, Y1 axis only Cond B or C , As applicable Per applicable RETS $\left(25^{\circ} \mathrm{C}, \mathrm{DC}\right)$ | 12 devices (no failures) |

## NOTES:

1. Samples subjected to this subgroup shall have been through the entire sequence of subgroup 6 testing.
2. All samples shall have seen 240 hours at $125^{\circ} \mathrm{C}$ (or equivalent)
3. Electrical measurements shall be recorded for those parameters for which deltas ( $\Delta$ ) are specified, and $\Delta$ 's will be computed.
4. Resubmission of failed lots shall be in accordance with paragraph 4.3.3.1 of MIL-M-38510.
5. Required only for packages containing a dessicant.

| TABLE III. GROUP D INSPECTION (PER METHOD 5005, TABLE IV) |  |  |  |
| :---: | :---: | :---: | :---: |
| TEST | $\begin{aligned} & \text { MIL_STD-883 } \\ & \text { METHOD } \end{aligned}$ | $\because$ CONDITIONS | $\begin{aligned} & \text { CLASS S LTPD } \\ & \text { AND B } \end{aligned}$ |
| Subgroup 1 <br> Physical dimensions Internal water vapor content | $\begin{aligned} & 2016 \\ & 1018 \end{aligned}$ |  | LTPD $=15$ <br> 15 devices (no failures) <br> 3 devices (no failures) |
| Subgroup 2 (note 1) <br> Lead integrity <br> Seal (fine and gross) | $\begin{aligned} & 2004 \\ & 1014 \end{aligned}$ | Test conditions B2 (lead fatigue) Cond B or $\mathrm{C}_{3}$ As applicable | $\begin{aligned} & \text { LTPD }=15 \\ & 15 \text { devices (no fallures) } \end{aligned}$ |
| Subgroup 3 <br> Thermal shock <br> Temperature cycling <br> Moisture resistance <br> Seal (fine and gross) <br> Visual examination <br> End point electrical parameters | $\begin{aligned} & 1011 \\ & 1010 \\ & 1004 \\ & 1014 \\ & 1004 \end{aligned}$ | Test condition B - $\mathbf{1 5}$ cycles Test condition C-100 cycles <br> Cond B or C, As applicable <br> Per applicable RETS (DC, $25^{\circ} \mathrm{C}$ ) | $\begin{aligned} & \text { LTPD }=5 \\ & 15 \text { devices (no fallures) } \end{aligned}$ |
| Subgroup 4 <br> Mechanical shock <br> Vibration variable frequency <br> Constant acceleration <br> Seal <br> Fine <br> Gross <br> Visual examination <br> End point electrical <br> parameters | $\begin{aligned} & 2002 \\ & 2007 \\ & 2001 \\ & 1014 \\ & 1010 \end{aligned}$ | Test condition 8 <br> Test condition A <br> Test condition E,Y1 axis only Cond B or C, As applicable <br> Per applicable RETS (DC, $25^{\circ} \mathrm{C}$ ) | $\begin{aligned} & 1 T P D=15 \\ & 15 \text { devices (no fallures) } \end{aligned}$ |
| Subgroup 5 (note 1) <br> Salt atmosphere <br> Seal (fine and gross) <br> Visual examination | $\begin{aligned} & 1009 \\ & .1014 \\ & 1009 \end{aligned}$ | Test condition A Cond $B$ or $C_{3}$ As applicable Paragraph 3.3.1 of Method 1009 | $L T P D=15$ <br> 15 devices (no tallures) |

Note 1: Electrical rejects from the same inspection lot may be used.
Note 2: Resubmission of failed lots shall be in accordance with paragraph 4.3.3.2 of MIL-M-38510.

TABLE IV WAFER LOT ACCEPTANCE

| TEST | LIMIT | SAMPLING PLAN | NOTES |
| :---: | :---: | :---: | :---: |
| 1. Wafer Thickness | Design Nominal $\pm 2$ mil ( $\pm .002$ inches) 6 mil (.006 inches) | Two Wafers <br> Per Wafer <br> Lot At Incoming inspection | 1 |
| 2. Metallization Thickness | Design Nominal $\pm 2 \mathrm{~K} \AA$ 8 KA Minimum For Single Level Metal and Top Layer of Multi-Level Metal. <br> $6 K \AA$ Minimum for Lower Level Metal Barrier Metal: $\pm 20 \%$ of Design Nominal | One Water Per Metallization Run. |  |
| 3. Thermal Stability | Bipolar: $\Delta \mathrm{V}_{\mathrm{FB}}$ or $\Delta \mathrm{V}_{\mathrm{T}} \leq 1.0 \mathrm{~V}$ | Once Per Month and After Each Tube Change | 2, 3 |
|  | MOS: $\Delta V_{F B}$ or $\Delta V_{T} \leq .5 \mathrm{~V}$ | Once Per Week and After Each Tube Change | 2,5 |
| 4. SEM | Per MIL-STD-883, Method 2018 | Two Wafers Per Metallization Run |  |
| 5. Glassivation Thickness | $\pm 20 \%$ From Design Nominal $6 \mathrm{~K} \AA$ Minimum | Two Wafers Or Test Chips Per Glassivated Lot |  |
| 6.GoldBacking Thickness | $4.5 \mathrm{~K} \AA$ Minimum 15K $\AA$ Maximum | One Wafer Per Lot | 4 |

## NOTES:

1. This test is not required when the finished wafer design thickness is greater than 10 mils (. 010 inches).
2. Required only for bipolar digital operating at 10 V or more, all linear, and all MOS.
3. For a wafer run to be acceptable, both the readings taken before and after the run must be verified.
4. Required only for gold-backed wafers.
5. For Rad Hard CMOS devices, this test will be performed on every wafer lot.

## National and Mil-M-38510

## Introduction

A major thrust exists among integrated circuit users, suppliers, and the U.S. Government to avoid proliferation of military procurement specifications by turning instead to standardized reliability processed products. National Semiconductor endorses and supports such trends.

One major program to which National is heavily committed is the JAN 38510 IC program. This is a standardization program administered by the U.S. Defense Department which allows a user to purchase a broad line of standard products from a variety of qualified suppliers.

There is only one 38510 program. National is committed to supplying only QPL devices, and discourages any '"pseudo-38510'" alternates.

The purpose of this brochure is to explain and clarify the program while highlighting its advantages and benefits to users.

There are three quality levels currently available - S, B, and C. S is typically specified for space flight application while B is used for aircraft and ground systems. C is sometimes specified for ground systems but, since it requires virtually all of the screening that $B$ requires (except burn-in), $B$ is most universally specified. This brochure concentrates on the requirement for $B$ level devices.

## Mil-M-38510

The Defense Electronic Supply Center (DESC) administers the integrated circuit standardization program known as Mil-M-38510, sometimes referred to as the JAN IC Program. The specification set used to define the program consists of four primary documents: general specification Mil-M-38510, which is a comprehensive definition of the detail processing and testing, referenced to Mil-STD-883 test methods to which IC devices produced under the program will be subjected; detail specifications, often referred to as '"slash sheets,' each of which explicitly defines the performance parameters of a unique generic device or a family of devices; Mil-STD-883, which defines specific screening procedures, and Mil-STD-976, which defines line certification requirements.

When a user orders a Mil-M-38510 device, he is guaranteed that he will get a device fully conformant with the detailed requirements and which has been subjected to the general testing and processing requirements. DESC requires semiconductor suppliers to become formally qualified under the 38510 program and listed on the current Qualified Products List (QPL) before they are allowed to legally ship JAN devices.

## Advantages to the User

The JAN 38510 program has numerous advantages for the integrated circuit user.

- A single explicit specification eliminates guesswork concerning what electrical characteristics or processing
flow the devices receive. (See Table 1 for details of the 38510 IC processing flow.)
- A rigorous schedule of quality conformance testing is a mandatory part of the Mil-M-38510 program, assuring the user that long-term reliability has been statistically sampled and documented.
- Since the electrical characteristics of the devices are at least as tight as the "standard industry data sheet" parameters, device performance will meet the vast majority of system design requirements. Additionally, there are more $\mathrm{min} / \mathrm{max}$ values in lieu of data sheet typicals, thus aiding in circuit design and worst case design analysis.
- The user is spared the expense of researching and preparing his own procurement document.
- The user is spared the expense of qualification testing. The QPL tells him which suppliers have qualified the devices he requires.
- The QPL gives the user a choice of qualified suppliers for devices that are fully interchangeable. In addition, the availability of several sources guarantees competitive pricing which will typically be lower than the pricing for devices to a user's own spec.
- Since 38510 is a standard program, procurement lead times will be shorter. With the vast proliferation of programs using JAN devices, distributors and manufacturers are increasing their inventories of JAN devices. National in particular is committed to maintaining finished goods and work-in-process inventories to support user needs.
- Spare parts will be readily available.
- Device markings are consistent from one manufacturer to another.
- The program is extremely cost effective. A user can purchase a few devices for engineering evaluation and prototyping and know that they will be identical to the devices he will get during production. When the cost factors associated with spec writing, supplier qualification, maintaining voluminous parts control documentation, and the more intangible benefits of device availability are totaled, use of JAN ICs is overwhelmingly the most cost effective approach.


## Advantages to the Supplier

What motivates a supplier like National to be so heavily committed to the 38510 program? National has the broadest range of reliability processed products available in the semiconductor industry. A program such as Mil-M-38510 helps to standardize the processing required and minimize the number of individual user specifications. This allows National to concentrate more resources on this program, thereby improving product quality and availability.

## Questions and Answers about 38510

There are many questions which we are frequently asked regarding the 38510 program. We would like to answer some of them for you.
Q. WHAT DOES A MANUFACTURER HAVE TO DO TO GET PARTS LISTED ON THE QPL?
A. There are two things which a manufacturer is required to do. First, he must get his facilities (including wafer fab, assembly, and rel processing areas) certified by DESC. This requires that each fab area used for QPL devices must be approved. Second, for each specific device and package combination listed on the QPL, the manufacturer must perform extensive qualification testing and provide detailed device information to DESC. This data is typically supplied in two phases. In the first phase, the manufacturer must supply detailed information concerning the device construction and electrical characteristics. Once this data bas been verified by DESC to confirm that the manufacturer's device meets the 38510 requirements, the manufacturer is listed on Part II of the QPL. At this point the manufacturer is legally able to supply full JAN qualified devices meeting ALL of the 38510 requirements. The manufacturer then must perform the full qualification testing of method 5005 of 883 as specified in paragraph 4.4 of 38510 . Once this data has been reviewed and accepted by DESC, the manufacturer is listed on Part I of the QPL.
Q. IS THERE ANY DIFFERENCE IN THE DEVICES A USER GETS FROM A MANUFACTURER WHO IS LISTED ON PART II OF THE QPL COMPARED TO THOSE FROM A MANUFACTURER ON PART I?
A. There is absolutely no difference. A supplier must meet all of the device screening and quality conformance requirements no matter what his QPL status.
Q. HOW DOES A USER KNOW WHAT DEVICES ARE COVERED BY THE SLASH SHEET SPECIFICATION?
A. Supplement 1 to Mil-M-38510 contains a listing of the slash sheet specifications and a cross reference to the generic part types. This is updated as new slash sheets are released.
Q. HOW DOES A USER GET COPIES OF THE QPL. SUPPLEMENT 1 OF 38510, MIL-M-38510 ITSELF, AND MIL-STD-883?
A. Copies of these and other related items may be obtained from: Naval Publications and Forms Center 5801 Tabor Avenue Philadelphia, PA 19120 (215) 697-2179
Q. WHAT HAPPENS WHEN A USER CANNOT OBTAIN HIS COMPLETE PARTS NEEDS FROM QPL LISTED DEVICES?
A. The ultimate aim of a standardization program must be to furnish all parts. Requests for addition of a part to 38510 should be made to DESC Directorate of Engineering, Dayton, Ohio 45444, indicating a need for slash sheets and/or suppliers to be qualified for the additional devices. National has a form (available through local sales offices) which may be used for this purpose. This form is shown in figure 1 . In addition, if only some parts are available, a user can still see significant savings on those that are available.
Q. HOW IS A JAN QPL DEVICE MARKED?
A. Tables II and III explain the details of the marking for JAN QPL ICs.
Q. ARE DEVICES CALLED 'M38510, JAN PROCESSED, JAN EQUIVALENT, ETC.' ' REALLY QPL PRODUCTS?
A. Absolutely not. There is only one QPL product - it is a JM38510 marked device. "JAN Equivalent" is expressly forbidden by paragraphs 3.1 and 3.6.7 of Mil-M-38510. National does not support these "equivalent" products.
Q. HOW LONG CAN A SUPPLIER REMAIN ON PART II OF THE QPL?
A. A manufacturer can remain on Part II for two years or until 30 days after another supplier becomes qualified for the same device package, screening level, and lead finish combination on Part I of the QPL.
Q. WHEN ANOTHER SUPPLIER OBTAINS PART I QUALIFICATION, ARE THE OTHER QUALIFIED SUPPLIERS REMOVED FROM PART II IMMEDIATELY?
A. No. The supplier is given 30 days before being removed from Part II. During that time a supplier may legally accept orders for those devices. After the end of the 30-day period, he may no longer accept orders but may complete and ship those orders received prior to that time, no matter how long it takes him to complete them.
Q. IS A SUPPLIER EVER REMOVED FROM PART I QUALIFICATION?
A. Generally not. As long as a supplier continues to manufacture the device, maintains appropriate facility approvals, and submits all required reports and information to DESC within stipulated time limits he will retain QPL I listing. Violation of these requirements can be cause for removal from QPL.
Q. CAN AN AUTHORIZED DISTRIBUTOR SHIP JAN DEVICES FROM HIS SHELVES IF THE MANUFACTURER HAS LOST HIS QPL LISTING FOR THOSE DEVICES?
A. Yes. As long as those devices were ordered by the authorized distributor while the manufacturer had QPL listing for those devices, the distributor may subsequently ship those devices from his shelves.
Q. CAN A MANUFACTURER LEGALLY SHIP JAN QPL mATERIAL HE ASSEMBLED AND TESTED BEFORE HE RECEIVED A QPL LISTING?
A. Yes. The manufacturer must assemble and screen parts to prove his ability to comply with the specifications before he can be placed on QPL. As a result, his first lot of material, which is fully conformant to QPL product requirements, will have a date code that is earlier than the date he is placed on the QPL.
Q. WHAT IS THE RELATIONSHIP BETWEEN MIL-M-38510 AND MIL-STD-883?
A. Mil-M-38510 defines complete program requirements and the detail device electrical performance parameters. The device processing requirements are specified using the test methods defined in Mil-STD-883.
Q. SUPPOSE DEVICES ARE KEPT ON A MANUFACTURER'S OR DISTRIBUTOR'S SHELVES FOR A PERIOD OF TIME; MUST THEY EVER BE RETESTED TO VALIDATE THAT THEY MEET SLASH SHEET CHARACTERISTICS?
A. Yes. Devices held by a manufacturer or his authorized distributor for more than 24 months must be retested by the manufacturer in accordance with Group A sampling requirements prior to shipment to a customer.
Q. WHY SHOULD A USER SPECIFY " $X$ " IN THE LEAD FINISH DESIGNATOR FOR A PART TYPE?
A. A manufacturer who receives an order for a specific lead finish for which he is qualified but has no inventory at the time of order may not be able to fill the order in a timely manner, even though he might have substantial inventory of another lead finish. Unless a user has a specific reason for wanting a particular lead finish, he should allow his suppliers the flexibility of shipping whatever finish is most readily available.
Q. WHAT DATA IS A MANUFACTURER REQUIRED TO SHIP WITH A JAN PART?
A. A certificate of conformance is all that is required. However, he must retain all data for three years.
Q. CAN A DEVICE FOR WHICH THERE IS NO SLASH SHEET BE PROCESSED TO 38510?
A. Since Mil-M-38510 invokes a combination of the processing requirements of Mil-STD-883 and the detail device performance parameters contained in each. individual slash sheet, the answer is obviously no. However, National's 883/RETS program provides parts which meet all of the screening requirements of the MIL-STD-883 specification.
Q. WHAT DOES A QPL LISTING LOOK LIKE AND HOW DO YOU READ IT?
A. Sample QPL listings are shown below:

## Government Designation

| Device Type | Device Class | Case Outline | Lead Mat \& Finish | Test Report Number | Manufacturer's Name (Address on Last Page) |
| :---: | :---: | :---: | :---: | :---: | :---: |
| JM38510/001 |  |  |  |  |  |
| 05 | B | A... | A or C | 38510-261-72 | National Semiconductor |
| 08 | C | C... | $B$ only |  | Corporation |
| JM38510/057 |  |  |  |  |  |
| 05 | B | E | B | 38510.93-77 | National Semiconductor |
|  | C | F | C |  | Corporation |

The first listing covers the following devices:

| JM38510/00105 | BAA | JM38510/00108 | BAA |
| :---: | :---: | :---: | :---: |
|  | BAC |  | BAC |
|  | BCB |  | BCB |
|  | CAA |  | CAA |
|  | CAC |  | CAC |
|  | CCB |  | CCB |
| The second listing covers the following devices: |  |  |  |
| JM38510/05705 | BEB | JM38510/05705 | CEB |
|  | BEC |  | CEC |
|  | BFB |  | CFB |
|  | BFC |  | CFC |

## Q. WHAT QUALITY CONFORMANCE TESTS ARE CONDUCTED? ARE ALL DEVICES IN A GENERIC FAMILY EVENTUALLY SUBJECTED TO QUALITY CONFORMANCE TESTING?

A. For B level devices quality conformance tests must be conducted as follows:
Group A — Each inspection lot.
Group B - Each inspection lot for each package type and lead finish on each detail specification.

Group C - Periodically at 90-day intervals on one device type or one inspection lot from each microcircuit group in which a manufacturer has qualified device types.
Group D - Periodically at a six-month interval for each package type for which a manufacturer holds qualifications.
Different devices within a generic family are chosen for successive quality conformance tests until all of the devices have been subjected to testing. The sequence is then repeated. The manufacturer must submit attributes data to DESC for all quality conformance tests performed. Tables IV, V, VI, and VII contain the details of the Group $\mathrm{A}, \mathrm{B}, \mathrm{C}$, and D tests respectively.
Q. HOW IS AN INSPECTION LOT DEFINED?
A. For Class B devices, each inspection lot shall consist of microcircuits of a single type, in a single package type and lead finish, or may consist of inspection sublots of several different types, in a single package type and lead finish, defined by a single detail specification. Each inspection lot shall be manufactured on the same production line(s) through final seal by the same production techniques, and to the same device design rules and case with the same material requirements, and sealed within the same period not exceeding six weeks.

Table I
JAN Device Processing Flow - Level B (per Method 5004 of MIL-STD.883)

| Screen | Method | Requirement |
| :---: | :---: | :---: |
| Internal Visual (Precap) | 2010 B | 100\% |
| Stabilization Bake | 1008, Test Condition C 24 hrs min | 100\% |
| Temperature Cycling | 1010, Test Condition C 10 cycles min | 100\% |
| Constant Acceleration | 2001, Test Condition E $Y_{1}$ axis, 30,000 Gs | 100\% |
| Hermetıcity <br> a. Fine <br> b. Gross | 1014 | 100\% |
| Interim Electrical Parameters | per Applicable Slash Sheet | 100\% |
| Burn in Test | 1015, 160 hrs at $125^{\circ} \mathrm{C}$ min | 100\% |
| Final Electrical Test a. Static Tests | per Applicable Slash Sheet PDA on static tests at $25^{\circ} \mathrm{C}$ is $10 \%$ | 100\% |
| 1. $25^{\circ} \mathrm{C}$ <br> 2. Max \& Min Rated Operating Temp |  |  |
| b. Dynamic Tests $25^{\circ} \mathrm{C}$ <br> c. Functional Test $25^{\circ} \mathrm{C}$ |  |  |
| Qualification or Quality Conformance Inspection | 5005 | Sample per Method 5005 |
| External Visual | 2009 | 100\% |



Table VI
Group C Inspection


Figure 1

## IC QUALIFICATION REQUEST FOR 38510 STANDARDIZATION PROGRAM

## TO:

Defense Electronics Supply Center
Dayton, Ohio 45444
Attention: Director Engineering Standardization, DESC E
FROM: $\qquad$
Name $\qquad$
Company $\qquad$
Address $\qquad$

Currently, I am defining requirements and preparing parts lists for the Program. For this program, I am attempting to utilize standard parts from the 38510 QPL list. Although I have been able to utilize some QPL listed parts, there are a number of devices for which slash sheets apparently have not yet been generated and/or for which there are no qualified sources. I have included those devices in the following list. I have also indicated the time frame in which I will need production quantities as well as the quality level.


Your help in setting appropriate priorities for generating these slash sheets and/or encouraging suppliers to become qualified will be beneficial to this program and is appreciated.

A space is provided to indicate the current status of each device. Please return the second page of this form to me.

Sincerely,

[^27]
## RADIATION HARDENED TECHNOLOGIES FROM NATIONAL SEMICONDUCTOR

For many years, military, aerospace and satellite programs have depended on bipolar transistor and integrated circuit technology in the fabrication of airborne systems. Development of bipolar technology is an outgrowth, in part, of avionics and space applications needs. Despite their relatively high immunity or resistance to high levels of both constant and burst radiation in the form of gamma rays, $x$-rays, cosmic rays, and so on, bipolar devices have one drawback: high power consumption, which adds to the power supply requirements and subtracts from the usable payload of spacecraft and missiles. The spacecraft and missile industry has long needed a radiation hardened logic technology with low power consumption. A second problem seen in this area has been the limited radiation tolerance of many linear devices. The purpose of this brochure is to provide some information to the potential user regarding National Semiconductor's solutions to both of these problems.

## CMOS Radiation Hardened Products

In recent years, the development of sophisticated space, satellite and military systems and mission requirements has fostered an active search for a radiation hardened logic circuit technology that consumes less power and offers a higher degree of circuit integration on a single silicon chip. Metal oxide semiconductor (MOS) devices, particularly complementary MOS (CMOS), seemed to promise just such an alternative. But standard CMOS devices, even those qualified to MIL-M-38510 (JAN) requirements, proved sensitive to relatively low radiation levels. Until recently, mass producible radiation hardened or resistant CMOS devices have been able to withstand only $10^{5}$ rads $(\mathrm{Si})^{1}$, while many space, satellite and missile systems require circuitry resistance levels at least ten times higher, $10^{6}$ rads ( Si ).

Now, National Semiconductor offers a solution to this problem: a complete line of megarad hardened CMOS logic products utilizing a radiation hardening process that is compatible with volume processing. Megarad hardened products [devices capable of tolerating total dose radiation of $10^{6}$ rads ( Si )] are the result of an intensive two-year research and development program which has enabled National Semiconductor to offer radiation hard versions of virtually our entire metal-gate CMOS product line.

Devices ranging in complexity from simple gates to large scale integration (LSI) random access memories have now been hardened using the processes we have developed. To achieve this level of radiation resistance in a mass production CMOS process, major modifications were made in the basic commercial process, relating to gate oxidation, substrate and P -tub surface concentrations, and metallization.

## Bipolar vs. CMOS

The inherently higher radiation resistance of bipolar over CMOS devices results from a basic difference in their structures. Bipolar devices are vertical structures. The basic elements-emitter, collector, and base-are laid down vertically, layer upon layer, by diffusion. As figure 1 shows, eurrent flows through

the bulk silicon, some distance below the silicon-silicon dioxide interface. Thus, there is some inherent protection from the interface effects of ionizing radiation in bipolar devices.

CMOS devices are surface effect devices. The equivalent operating elements, gate, source and drain, are at the surface, and the flow of current occurs horizontally across the device, very close to the silicon-silicon dioxide interface. Changes in interface parameters created by the introduction of surface ionic charge during gamma or $x$-radiation have a first order effect on MOS transistor performance, in contrast to the second order effect they have on bipolar devices. Thus, the basic physics of CMOS transistor structures needs to be addressed to minimize ionizing radiation effects without substantially impacting performance.

[^28]

FIGURE 2: CMOS IC TRANSISTORS

## CMOS Transistor Structure

Complementary MOS, or CMOS, combines two types of MOS devices, P-channel and N-channel structures, into a single functioning unit. The lower power dissipation and high stability resulting from this complementary combination is particularly attractive in the design of portable battery-powered electronic units, or for applications where a battery provides standby power.

MOS structures, both N - and P-types, perform in two modes; enhancement and depletion. In a P-channel enhancement mode MOS device, for example, the gate controls the current flow between the source and drain. In this device, when a negative voltage is applied to the gate with respect to the source, a field is set up accross the gate dielectric, producing a positively charged conductive path, a channel, between the source and the drain. This is known as an enhancement mode device because zero gate to source voltage turns off the device. In the alternative mode, depletion, current flows despite the gate voltage being zero, because sufficient field is still present within the gate to induce a conductive path between the device source and drain regions. the N -channel MOS transistor is similar to the P-channel alternative, except that positive voltage applied to the gate, with respect to source, induces a negatively charged conductive path between source and drain to turn the device on.

Conventional CMOS logic circuits are produced with only enhancement mode N - and P-channel devices. The process is designed to give turn on (threshold) voltage values for both types of devices which insure proper circuit perfor-

mance. Figure 3 illustrates the cross section of a CMOS structure connected in a simple inverter configuration. To form the standard metal gate CMOS structure, a lightly doped P-tub is formed by diffusion into an $N$-type subtrate with the tub becoming the subtrate for the N -Channel transistor. The $\mathrm{N}+$ and $\mathrm{P}+\mathrm{im}$ purities are diffused into P-tub and N -substrates to become the N - and P - channel transistors' source and drain regions, respectively. These diffusions also serve as contacting regions to the positively biased $N$-substrate and the normally grounded P-tub regions (VDD and VSS respectively).

A gate oxide is grown such that a thin film of dielectric oxide material bridges the source/drain regions over the entire circuit. Finally, contact apertures are etched to the source/drain regions and an aluminum film evaporated and etched to form gate electrodes, contacts to device terminals, and interconnection conductor lines.

## Effects of lonizing Radiation

A CMOS transistor's radiation resistance is primarily determined by formation of the gate structures in both P-channel and N-channel devices. The gate structures are used to turn the MOS devices on or off; that is, to start or stop a flow of current from the source to the drain. Ionizing radiation induces unwanted positive charge into the gate oxide structure, resulting in lowering the threshold voltage of actual circuit devices and parasitic field oxide devices by values of as much as 30 V or more. Figure 4 shows the charge buildup


FIGURE 4. CHARGE BUILD.UP MECHANISMS IN AN N-CHANNEL GATE OXIDE DURING IRRADIATION UNDER WORST CASE BIAS.
mechanisms in an N -channel gate oxide during irradiation under worst case bias. In establishing a radiation hardened CMOS process, it is necessary to incorporate processing steps which minimize these radiation induced shifts in critical locations of the IC structure.

The impact of radiation induced oxide charge on operating CMOS devices is to decrease the N -channel threshold voltage, VTN, and increase the magnitude of the P -channel threshold voltage, VTP. The most serious problem occurs when sufficient reduction in VTN occurs to cause the N -channel device to go from enhancement to depletion mode operation. This results in excessive power supply current drain and loss of circuit functionality. The most severe stress on an N -channel device occurs when its gate is positively biased during irradiation. This causes positive charge in the oxide to be driven closer to the $\mathrm{Si}-\mathrm{SiO}_{2}$ interface where it is more effective in causing the P-type substrate surface to become inverted to N -type.
In normal operation, positive bias does not appear between the gate and substrate of P-channel devices since the substrate is already at the most positive circuit potential, VDD. The most severe effect on P-channel devices during irradiation often occurs with zero gate to substrate bias. This stress creates $\mathrm{Si}-\mathrm{SiO}_{2}$ interface states which are capable of holding a positive charge with negative voltage applied to the gate. This increases the absolute value of $V_{T P}$, but is a much less deleterious effect to the circuit than the $V_{T N}$ shift.

## CMOS Process Modification

## Gate Oxidation

To minimize both the radiation induced positive oxide charge and formation of $\mathrm{Si}-\mathrm{SiO}_{2}$ interface states, a dry rather than wet oxidation step is used. The gate oxide is thermally grown in a pure oxygen atmosphere, rather than in a steam atmosphere, as is the case in some metal gate fabrication processes. Moreover, the gate oxide is thermally grown at $1000^{\circ} \mathrm{C}$, followed by a nitrogen anneal at $850^{\circ} \mathrm{C}$. This cycle has been empirically found to produce oxides having a high degree of resistance to ionizing radiation effects as well as excellent pre-radiation MOS characteristics ${ }^{2}$. The need for thermally growing gate oxides at $1000^{\circ} \mathrm{C}$ in dry oxygen for optimal radiation hardness is one of the more intriguing aspects of this experimentally deduced cycle.

## Metallization

A by-product of the E-beam aluminum evaporation process commonly used in commercial IC fabrication is soft $X$-radiation. This radiation produces the same type of positive charge in the gate oxide and interface states which a radiation hardened oxide should resist. Although these harmful effects in the gate oxide can be removed by a high temperature anneal cycle, subsequent exposure of the oxide to ionizing radiation results in a drastically less radiation resistant' structure. Use of a non-E-
beam metallization technique circumvents the problem of high threshold shifts due to irradiation under zero and negative gate bias associated with soft $X$-ray damage. For this reason, induction heated evaporation of aluminum is used to fabricate radiation hardened CMOS products.

## Substrate and $\mathbf{P}$ - Tub Surface

The deleterious effect of ionizing radiation on VTN and VTP values in a CMOS device can be minimized through process modification. In anticipation of these threshold voltage shifts, radiation hardened CMOS devices are designed with the initial value of $V_{T N}$ as high as possible and VTP as close to zero as possible without sacrificing pre-radiation circuit performance. Both the substrate resistivity and the P-tub surface concentration have been modified with the initial value of $V_{T N}$ being increased to 1.8 volts from the standard value of 1.3 volts and $V$ TP being changed from the standard -1.7 volts to -1.3 volts.

## Performance Characteristics

All of the data given in Figures 5 through 10 was generated from the parts listed in Table A. Figures 5 through 8 illustrate the variation of post radiation $V_{T N}$ and $V_{T P}$ with dose. The distribution of the $V_{T N}$ and VTP data is found to be normal both before and after irradiation. The solid line shows the mean value of $\mathrm{V}_{\mathrm{TN}}$ (or


[^29]VTP），and the dashed lines indicate one standard deviation on either side of the mean．This value， for both N －and P －channel devices，remains fairly constant from the unirradiated state through $10^{6}$ rads（ Si ）dosaje．The values shown remain


FIGURE 7：VTP VS．DOSE

well above the 300 mV VTN lower limit，which，if penetrated，would lead toward N －channel deple－ tion mode behavior and risk of losing circuit func－ tionality and excessive supply current drain．


FIGURE 9：ISS vS．DOSE

Figure 9 illustrates the supply quiescent cur－ rent（Iss）variation as a function of dose．Since ISS is a function of die size，curves have been plotted for three levels of integration，SSI，MSI and LSI．In all cases，the leakage level at $10^{6}$ rads（ Si ）does not increase by more than an order of magnitude from the initial value．The end point at $10^{6}$ rads（ Si ）for LSI of $30 \mu \mathrm{~A}$ is far below the high temperature $\left(125^{\circ} \mathrm{C}\right)$ specifica－ tion of $600 \mu \mathrm{~A}$ for standard devices．The same results can be seen with MSI and SSI．



Figure 10 illustrates circuit propagation delay, tpD, as a function of dose. The plot, similar to Figure 9, is divided into three categories (LSI, $\mathrm{MSI}, \mathrm{SSI}$. The propagation delay value at $10^{6}$ rads (Si) for all three categories increased roughly $20-25 \%$ from the initial value, well within desirable operating tolerances. In Figures 5 through 10, the biasing conditions during irradiation were: $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V} I \mathrm{~N}=10 \mathrm{~V}$, $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$.

## Hardness Assurance and Reliability

A sampling plan has been established to ensure radiation hardness to $10^{5}$ and $10^{6}$ rads, since ionizing radiation degrades IC performance and cannot be used for $100 \%$ screening. In addition, an intensive program to evaluate the reliability characteristics of radiation hardened CMOS circuits is underway. 476 devices of the CD4001AD-RH, CD4011AD-RH, and MM54C200-RH types have been tested and have operated for over 800,000 hours without a failure. This corresponds to a failure rate less than $0.125 \% / 1000$ hours at $125^{\circ} \mathrm{C}$ with a $60 \%$ confidence level.

Table $B$ outlines the plan used to assure hardness of devices built from a given wafer lot. Sample devices are assembled in accordance with sampling plan $A$ or $B$, depending on whether $10^{5}$ or $10^{6}$ rads ( Si ) hardness, respectively, is required. Sample devices are tested, irradiated, and retested, and must pass the appropriate post-radiation electrical limits outlined in Table $C$ for the production lot to be qualified. The production units are capable of

| TABLE B. HARDNESS ASSURANCE PLAN |  |
| :---: | :---: |
| I. Plan A |  |
| Sample Size (Wafers) | 2 |
| Sample Size (Devices/Wafer) | 3 |
| Total Devices Irradiated | 6 |
| Accept Level | 0 Rejects |
| Heject Level | 1 Reject |
| II. Plan 8 |  |
| Sample | Each wafer |
| Sample Size (Devices/Wafer) | 3 |
| Accept Level | 0 Rejects per Wafer |
| Reject Level | 1 Reject per Wafer |
| III. Product Flow: |  |
| A. For $1 \times 10^{5}$ rads ( Si ) quallification: |  |
| 1. Qualify lot with Plan A <br> 2. If lot fails, qualify wafers individually with Plan B |  |
| B. For $1 \times 10^{6}$ rads (Si) qualification: <br> 1. Qualify wafers individually with Plan B |  |

meeting MIL-M-38510 electrical test limits, when available, as well as National's RETS limits.

## Extended Total Dose Rate [to $\mathbf{1 0}^{\mathbf{7}}$ Rads (Si)]

Much of the data generated in the course of our testing indicates that the resistance of our CMOS products extends at least one order of magnitude above the $10^{6}$ level already demonstrated. Figures 11 and 12 illustrate


Figure 11: variation of Vtn and vtp with radiation
dOSE-EXTENDED TO $\mathbf{1 0}^{7}$ RadS ( Si )
measured shifts from pre-irradiation values in P . and N -channel threshold voltage, $\mathrm{V}_{\text {TP }}$ and $V_{T N}$, respectively, up to total dose levels of $10^{7}$ rads (Si). Of special interest is the change in slope of the VTN versus dose characteristic at levels just above the $10^{6}$ rads (Si).

At this level, negative charge from the silicon substrate arrives in the gate oxide at a rate faster than radiation-created positive charge.


This causes $V_{T N}$ to return toward its initial value as dose level is increased even further while increases in VTP still remain within reasonable limits for satisfactory circuit operation.

## Dose Rate Performance

When CMOS ICs are subjected to large bursts of ionizing radiation, hole-electron pairs are created in the silicon substrate. The resultant current flowing through the high resistivity P -and N -substrates can cause voltage differences which may impair circuit performance in one of the following ways.

One: LATCH-UP.
A CMOS circuit contains the structural elements required to form a four layered Schockley diode switching device as illustrated

TABLE C. POST•RADIATION SPECIFICATION*

| TABLE C. POST.RADIATION SPECIFICATION* |  |  |
| :---: | :---: | :---: |
| PARAMETER | $\text { POST } 10^{5} \text { RADS }$ <br> (SI) | $\text { POST } 10^{6} \text { RADS }$ <br> (Si) |
| Threshold Voltage $\begin{aligned} & V_{T N} \\ & V_{T P} \\ & \hline \end{aligned}$ | $\begin{aligned} & 0.45 \mathrm{~V}(\min ) \\ & 2.50 \mathrm{~V}(\max ) \\ & \hline \end{aligned}$ | $\begin{aligned} & 0.20 \mathrm{~V}(\min ) \\ & 2.80 \mathrm{~V}(\text { max }) \end{aligned}$ |
| Quiescent Current <br> (ISS), $V_{D D}=10 \mathrm{~V}$ Gates Flip-Flops MSI LSI | $2.0 \mu \mathrm{~A}$ (max) 5.0 $\mu \mathrm{A}$ (max) $15.0 \mu \mathrm{~A}$ (max) $50.0 \mu \mathrm{~A}$ (max) | $10.0 \mu \mathrm{~A}$ (max) $20.0 \mu \mathrm{~A}$ (max) $50.0 \mu \mathrm{~A}$ (max) $100.0 \mu \mathrm{~A}$ (max) |
| $\begin{aligned} & \text { Prop Delay, } \\ & V_{D D}=10 \mathrm{~V}, \\ & C D=50 \mathrm{pF} \end{aligned}$ | $\begin{gathered} <\mathbf{2 5 \%} \\ \text { degradation } \\ \text { from pre-rad } \\ \text { spec } \end{gathered}$ | $<45 \%$ <br> degradation from pre-rad spec |
| *Gamma irradiation from a Cobalt-60 source, worst case biasing at $V_{D D}=10$ volts. |  |  |



RGure 13. CROSS SECtion of cmos circuit elements which may lead to latch-up DURING IONIZING RADIATION BURSTS.
in Figure 13. The emitter-base junctions of the lateral PNP and vertical NPN which comprise the Schockley diode are normally prevented from becoming forward biased by the circuit metallization. Because of this, the Schockley diode will be in the off state during normal circuit operation and will pose no threat to reliable circuit performance.

Sufficiently high values of burst radiation can cause currents to flow through substrate resistances, $R_{N}$ - and $R_{P}$, to cause forward biasing of the parasitic PNP and NPN emitterbase junctions and turn on the Schockley diode. The excessive flow of supply current


FIGURE 14: LATCH-UP EQUIVALENT CIRCUIT FOR BULK CMOS STRUCTURE
which accompanies turn-on of the Schockley diode has been found to occur in the range of $10^{8}$ to $10^{10}$ rads $(\mathrm{Si}) / \mathrm{sec}$ on many CMOS circuits.

The basic circuit required for latch-up to occur is illustrated in figure 14. It consists of a parasitic bipolar NPN and PNP transistor sharing a common collector-base junction. The two requirements necessary for turn on of this device are:

1. The product of the common emitter current gains of the two devices, $\beta$ PNP and $\beta$ NPN, must satisfy the relationship $\beta$ NPN $-\beta P N P \geq 1$, and
2. The emitter-base junction of the two transistors must become forward biased to about 0.6 V or greater.

In normal operation, condition No. 1 will be met, but condition No. 2 will not be met, permitting latch-up free operation.

This problem can be completely eliminated by reducing to less than unity the product of the common emitter current gains of the NPN and PNP devices comprising the Shockley diode. One technique which has been successfully employed to eliminate the latch-up problem has been the use of neutron irradiation to lower minority carrier lifetime in the silicon substrate which directly affects parasitic bipolar current gains. As the values in Table $D$ indicate,

| TABLE D. LATCH.UP PERFORMANCE |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| DEVICE | VDD | DOSE REQUIRED FOR LATCH-UP |  | UNITS |
|  |  | CONTROL (NON NEUTRON TREATED) | NEUTRON TREATED* |  |
| CD4006 | 10V | $>9.4 \times 10^{9}$ | $>9.4 \times 10^{9}$ |  |
| CD4011 | 10V | $3.1 \times 10_{0}^{9}$ | $>9.4 \times 10_{0}^{9}$ | Rads (Si)/sec |
| CD4012 | 10V | $2.0 \times 10_{8}^{9}$ | $>2.4 \times 10_{0}^{9}$ | Rads (Si)/sec |
| CD4053 MM54C200 | 10 V 5 V | $\begin{aligned} 3.2 & \times 10^{8} \\ > & 2.2 \times 10^{10}\end{aligned}$ | $\begin{aligned} & >9.4 \times 10^{9} \\ & >8.8 \times 10^{11} \end{aligned}$ | Rads (Si)/sec <br> Rads (Si)/sec |
| MM54C200 | 5 V | $\geq 2.2 \times 10^{0}$ | $>8.8 \times 10^{11}$ | Rads (Si)/sec |
| *Neutron treated parts were subjected to a neutron flux of $1 \times 10^{14}$ neutrons (fast)/ $\mathrm{cm}^{2}$. |  |  |  |  |

neutron treatment of parts which exhibit latchup at $3 \times 10^{8}$ and $3 \times 10^{9}$ rads $(\mathrm{Si}) / \mathrm{sec}$ resulted in latch-up free operation up to the limit of the burst simulation equipment, $10^{10}$ rads ( Si )/sec. By treating wafers with neutron fluxes on the order of $10^{14} / \mathrm{cm}^{2}$, this enhanced circuit performance is obtained without sacrificing parametric performance. This is illustrated in Figures 15 and 16 , which plot supply current drain and propagation delay, respectively, versus neutron flux and show no significant degradation at the $10^{14} / \mathrm{cm}^{2}$ level.


DEVICE USED MM54C200D/RH
(256-BIT RAM)
Figure 15: device ouiescent supply current vs. neutron flux.


DEVICE USED: MM54C200D:RH
(256-BIT RAM)
figure 16: PROPAGAtion delay vs. neutron flux.

Another method which may be used to reduce minority carrier lifetime and achieve latch-up free operation is the use of gold doping in the wafer fabrication process in order to reduce the current gain product to below unity and thus insure latch-up free operation. This approach is presently being investigated in the National Semiconductor development laboratory.

## Two: DATA.UPSET

This effect results in the loss of stored data in a circuit after being subjected to burst radiation. It is typically of most concern in circuits such as memories and shift registers, where stored data bits are not directly coupled to circuit inputs. The problem is apparently caused during ionizing burst radiation exposure when one or more of the circuit's parasitic bipolar devices becomes turned on and causes asymmetric current flows in the data storage circuit, leading to a reversal of the stored data state.

Table E shows the effect that neutron treatment of an MM54C200D/RH 256-bit static RAM has on the dose rate at which upset occurs. The effect of gain degradation of parasitic devices on data upset is not nearly as dramatic as it is in the case of latch-up. Although neutron fluxes in excess of $10^{15} / \mathrm{cm}^{2}$ cause significant alterations in semiconductor material properties and circuit electrical parameters, Figures 15 and 16 indicate that the circuits tested would still meet data sheet requirements after irradiation in excess of $2 \times 10^{15} / \mathrm{cm}^{2}$. At this level the tolerance to data upset exhibits about a threshold improvement over untreated devices. Almost an entire order of magnitude improvements in data upset tolerance can be obtained with treatment at $10^{16} / \mathrm{cm}^{2}$ if the user can tolerate the degraded propagation delay and increased supply current drain occurring at this level.

## RAD Hard CMOS Reliability

Radiation hardness, however, is of no value to the system user if it is accomplished at the sacrifice of device reliability. To confirm device reliability, each of 476 units from five lots were subjected to 2,016 hours of burn-in at $125^{\circ} \mathrm{C}$. The results of this testing are shown in Table F.

The two asterisked lots received a 168 hour pre burn-in prior to the operating life test. The total device hours were 804,384 which represents a
projected $0.11 \% / 1000$ hours failure rate at a $60 \%$ confidence level. This falls well within the reliability requirements of even the most stringent programs.

In addition to this initial sampling, $100 \%$ burnin screening, as well as operating life testing, has been performed on many lots that have been produced for various customers. The results of this additional testing have continued to demonstrate that rad hard devices are as reliable as the Table F data indicates.

## Radiation Hardened Linear Devices

Although most bipolar logic devices tend to be inherently hard when exposed to total-dose radiation, many bipolar linear devices will begin to degrade when exposed to relatively low levels of radiation. The causes are similar to those seen in MOS radiation exposure related
failures. Linear devices, unlike most bipolar technologies, utilize lateral transistors as well as vertical transistors. Lateral transistors suffer from beta degradation as a result of the oxide and interface charges induced by high levels of radiation.

The solution to linear radiation problems, however, is quite different than what we have described above for CMOS devices. Total modification of the fabrication process is needed in order to achieve megarad hardness on linear devices. We have developed megarad versions of the LM108A and LM101A, with other devices now in development. We have extensive research and development currently underway in this area, for we feel that a broad line of rad hard linear devices is essential if systems designers are to achieve total systems hardness.

| TABLE F. RAD HARD OPERATING LIFE RESULTS |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DEVICE <br> TYPE | SAMPLE SIZE | $V_{\text {DD }}$ | REJECTS |  |  |  |  |
|  |  |  | 168 HR. | 336 HR. | 504 HR. | 1008 HR. | 2016 HR. |
| CD4001AD* | 115 | +15V | 0 | 0 | 0 | 0 | 0 |
| CD4001AD | 119 | +12V | 0 | 0 | 0 | 0 | 0 |
| CD4001AD | 112 | +12V | 0 | 0 | 0 | 0 | 0 |
| CD4001AD | 90 | + 12V | 0 | 0 | 0 | 0 | 0 |
| MM54C200D* | 40 | $+12 \mathrm{~V}$ | 0 | 0 | 0 | 0 | 0 |
| TOTAL: | 476 |  | 0 | 0 | 0 | 0 | 0 |
| *Received 168 hour burn-in prior to operating life test. |  |  |  |  |  |  |  |

RAD Hard CMOS

| Device | Series | Device | Series | Device | Series | Device | Series | Device |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CD4001 | A/B | CD4018 | B | CD4040 | A | CD4071 | B | MM54C04 |
| CD4002 | A | CD4019 | B | CD4041 | A | CD4073 | B | MM54C14 |
| CD4006 | A | CD4020 | A | CD4042 | B | CD4075 | B | MM54C86 |
| CD4007 | A | CD4021 | A | CD4043 | A | CD4076 | B | MM54C173 |
| CD4008 | B | CD4022 | B | CD4044 | A | CD4081 | B | MM54C174 |
| CD4009 | A | CD4023 | A/B | CD4048 | B | CD4093 | B | MM54C192 |
| CD4010 | A | CD4024 | B | CD4049 | A | CD40106 | B | MM54C193 |
| CD4011 | A | CD4025 | A/B | CD4050 | B | CD40174 | B | MM54C200 |
| CD4012 | A | CD4027 | B | CD4051 | B | CD40192 | B | MM54C901 |
| CD4013 | B | CD4028 | B | CD4052 | B | CD40193 | B | MM54C902 |
| CD4014 | A | CD4029 | B | CD4053 | B | CD4514 | B | MM54C903 |
| CD4015 | A | CD4030 | A | CD4066 | B | CD4515 | B | MM54C904 |
| CD4016 | A | CD4031 | B | CD4069 | A | CD4518 | B | MM54C906 |
| CD4017 | B | CD4035 | B | CD4070 | B | CD4584 | B | MM54C907 |

Table G. Radiation Hardened CMOS
Qualified Parts List
Devices Hard to $10^{6}$ Rads (Si)

## A+ Program

A+ Program: A comprehensive program that utilizes National's experience gained from participation in the many Military/Aerospace programs.
A program that not only assures high quality but also increases the reliability of molded integrated circuits.

The A+ program is intended for users who cannot perform incoming inspection of ICs or do not wish to do so, yet need significantly better than usual incoming quality and higher reliability levels for their standard integrated circuits.
Users who specify A+ processed parts will find that the program:

- Eliminates incoming electrical inspection.
- Eliminates the need for, and thus the added cost of, independent testing laboratories.
- Reduces the cost of reworking assembed boards.
- Reduces field failures.
- Reduces equipment down time.
- Reduces the need for excess inventories due to yield loss incurred as a result of processing performed at independent testing laboratories.


## The A+ Program Saves You Money

It is a widely accepted fact that down-time of equipment is costly not only in lost hours of machine usage but also costly in the reapir and maintenance cycle. One of the added advantages of the A+ program is the burn-in screen, which is one of the most effective screening procedures in the semiconductor industry. Failure rates as a result of the burn-in can be decreased many times. The objective of burn-in is to stress the device much higher that it would be stressed during normal usage.

The concept of reliability, on the other hand, refers to how well a part that is initially good will withstand its environment. Reliability is measured by the percentage of parts that fail in a given period of time.
Thus the difference between quality and reliability means the ICs of high quality may, in fact be of low reliability, while those of low quality may be of high reliability.

## Improving the Reliability of Shipped Parts

The most important factor that affects a part's reliability is its construction: the materials used and the method by which they are assembled.

Reliabilty cannot be tested into a part. Still, there are tests and procedures that an IC vendor can implement which will subject the IC to stresses in excess of those that it will endure in actual use, and which will eliminate marginal, short-life parts.
In any test of reliability the weaker parts will normally fail first. Further, stress tests will accelerate, or shorten, the time of failure of the weak parts. Because the stress tests cause weak parts to fail prior to shipment to the user, the population of shipped parts will in fact demonstrate a higher reliability in use.

## National's A+ Program

National has combined the successful B+ program with the Military/Aerospace processing specifications and provides the A+ program as the best practical approach to maximum quality and reliability on molded devices. The following flow chart shows how we do it step by step.

## Reliability vs. Quality

The words "reliability" and "quality" are often used interchangeably, as though they connoted identical facets of a product's merit. But reliability and quality are different, and IC users must understand the essential difference between the two concepts in order to evaluate properly the various vendors' programs for products improvement that are generally available, and National's A+ program in particular.
The concept of quality gives us information about the population and faulty IC devices among good devices, and generally relates to the number of faulty devices that arrive at a user's plant. But looked at in another way, quality can instead relate to the number of faulty ICs that escape detection at the IC vendor's plant.
It is the function of a vendor's Quality Control arm to monitor the degree of success of that vendor in reducing the number of faulty ICs that escape detection. Quality Control does this by testing the outgoing parts on a sampled basis. The Acceptable Quality Level (AQL) in turn determines the stringency of the sampling. As the AQL decreases it becomes more difficult for defective parts to escape detection, thus the quality of the shipped parts increases.

High Temperature $\left(100^{\circ} \mathrm{C}\right)$ Functional Electrical Test A high temperature test with voltages applied places the die under the most severe stress possible. The test is actually performed at $100^{\circ} \mathrm{C}-30^{\circ} \mathrm{C}$ higher than the commercial ambient limit. All devices are thoroughly exercised at the $100^{\circ} \mathrm{C}$ ambient.

## Electrical Testing

Every device is tested at $25^{\circ} \mathrm{C}$ for functional and DC parameters.

Burn-in Test
Devices are stressed at maximum operating conditions to eliminate marginal devices. Test is performed per Mil-Std-883B Method 1015.3.

## DC Functional and Parametric Tests

These room-temperature functional and parametric tests are the normal, final tests through which all National products pass.

## Thermal Shock Monitor

Samples from each package type are selected at random each week and submitted to 100 cycles of liquid to liquid thermal shock $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$. In addition, samples are selected every four weeks and subjected to 2000 temperature cycles of $0^{\circ} \mathrm{C}$ to $+25^{\circ} \mathrm{C}$.

Tighter-than-normal QC Inspection Plans
Most vendors sample inspect outgoing parts to a $0.3 \%$ AQL. When you specify the A+ program, we sample your parts to a $0.035 \%$ AQL at room temperature and $0.05 \% \mathrm{AQL}$ at $\mathrm{T}_{\mathrm{A}}$ Max. This eight times tightening (from 0.3 to $0.035 \%$ AQL) coupled with three $100 \%$ electrical tests, dramatically reduces the number of "escapes" and allows us to guarantee the AQLs listed below.

## Ship Parts

Here are the QC sample plans used in our A+ test program:

| Test | Temperature | AQL |
| :--- | :---: | :---: |
| Electrical Functionality | $25^{\circ} \mathrm{C}$ |  |
| Parametric, DC | $25^{\circ} \mathrm{C}$ |  |$\}$

## B+ Program

B+ Program: a comprehensive program that assures high quality and high reliability of molded integrated circuits.

The $\mathrm{B}+$ program improves both the quality and the reliability of National's digital, linear, and CMOS Epoxy B integrated circuit products. It is intended for the manufacturing user who cannot perform incoming inspection of ICs, or does not wish to do so, yet needs significantly-better-than-usual incoming quality and reliability levels for standard ICs.

Integrated circuit users who specify B+ processed parts will find that the program:

- Eliminates incoming electrical inspection.
- Eliminates the need for, and thus the added cost of, independent testing laboratories.
- Reduces the cost of reworking assembed boards.
- Reduces field failures.
- Reduces equipment down time.


## Reliabilty Saves You Money

With the increases population of integrated circuits in modern electronic systems has come an increased concern with IC failures in such systems.

And rightly so, for at least two reasons.
First of all, the effect of component reliability on system reliability can be quite dramatic. For example, suppose that you, as a system manufacturer, were to choose an IC that is 99 percent reliable. You would find that if your system used only 70 such ICs, the overall reliability of the system's IC portion would be only 50 percent. In other words, only one out of two of your systems would operate. The result? A system very costly to produce and probably very difficult to sell.

Secondly, whether the system is large or small you cannot afford to be hounded by the spectre of unnecessary maintenance costs. Not only because labor, repair, and rework costs have risen - and promise to continue to rise - but also because field replacement may be prohibitively expensive. If you ship a system that contains a marginally-performing IC, an IC that later fails in the field, the cost of replacement may be - literally hundreds of times more than the cost of the failed IC itself.

## Improving the Reliability of Shipped Parts

The most important factor that affects a part's reliability is its construction: the materials used and the method by which they are assembled.
Now, it's true that reliability cannot be tested into a part. Still, there are tests and procedures that an IC vendor can implement, which will subject the IC to stresses in excess of those that it will endure in actual use, and which will eliminate most marginal, short-life parts.

In any test for reliabilty the weaker parts will normally fail first. Further, stress tests will accelerate, or shorten, the time to failure of the weak parts. Because the stress tests cause weak parts to fail prior to shipment to the user, the population of shipped parts will in fact demonstrate a higher reliability in use.

## Quality Improvement

When an IC vendor specifies 100 percent final testing of its parts then, in theory, every shipped part should be a good part. However, in any population of mass-produced items there does exist some small percentage of defective parts.

One of the best ways to reduce the number of such faulty parts is, simply, to retest the parts prior to shipment. Thus, if there is a one percent chance that a bad part will escape detection initially, retesting the parts reduces that probability to only 0.01 percent. (A comparable tightening of the QC group's sampled-test plan ensures the maintenance of the improved quality level.)

## National's B+ Program Gets It All Together

We've stated that the B+ program improves both the quality and the reliability of National's molded integrated circuits, and pointed out the difference between those two concepts. Now, how do we bring them together? The answer is in the $\mathrm{B}+$ program processing, which is a continuum of stress and double testing. With the exception of the final QC inspection, which is sampled, all steps of the $B+$ process are performed on 100 percent of the program parts. The following flow chart shows how we do it, step by step.


SEM
Randomly selected wafers are taken from production regularly and subjected to SEM analysis.

## Epoxy B Processing for All Molded Parts

At National, all molded semiconductors, including ICs, have been built by this process for some time now. All processing steps, inspections, and QC monitoring are designed to provide highly reliable products. (A reliability report is available that gives, in detail, the background of Epoxy B, the reason for its selection at National, and reliability data that proves its success.)

## Six Hour, $150^{\circ} \mathrm{C}$ Bake

This stress places the die bond and all wire bonds into a combined tensile and shear stress mode, and helps eliminate marginal bonds and electrical connections.

High Temperature $\left(100^{\circ} \mathrm{C}\right)$ Functional Electrical Test A high temperature test such as this with voltages applied places the die under the most severe stress possible. The test is actually performed at $100^{\circ} \mathrm{C}$ -
$30^{\circ} \mathrm{C}$ higher than the commercial ambient limit. All devices are thoroughly exercised at the $100^{\circ} \mathrm{C}$ ambient. (Even though Epoxy B processing has virtually eliminated thermal intermittents, we perform this test to ensure against even the remote possibility of such a problem. Remember, the emphasis in the $\mathrm{B}+$ program is on the elimination of those marginally-performing devices that would otherwise lower field reliability of the parts.)

## DC Functional and Parametric Tests

These room-temperature functional and parametric tests are the normal, final tests through which all National products pass.

## Thermal Shock Monitor

Samples from each package type are selected at random each week and submitted to 100 cycles of liquid to liquid thermal shock $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$. In addition, samples are selected every four weeks and subjected to 2000 temperature cycles of $0^{\circ} \mathrm{C}$ to $+25^{\circ} \mathrm{C}$.

## Tighter-than-normal QC Inspection Plans

Most vendors sample inspect outgoing parts to a $0.3 \%$ AQL. When you specify the B+ program, we sample your parts to a $0.035 \%$ AQL at room temperature and $0.05 \% \mathrm{AQL}$ at $\mathrm{T}_{\mathrm{A}} \mathrm{Max}$. This eight times tightening (from 0.3 to $0.035 \%$ AQL) coupled with two $100 \%$ electrical tests, dramatically reduces the number of "escapes" and allows us to guarantee the AQLs listed below.

Ship Parts

Here are the QC sampling plans used in our B+ test program:

| Test | Temperature | AQL |
| :---: | :---: | :---: |
| Electrical Functionality | $25^{\circ} \mathrm{C}$ | 0.035\% |
| Parametric, DC | $25^{\circ} \mathrm{C}$ | 0.035\% |
| Parametric, AC | $25^{\circ} \mathrm{C}$ | 0.4\% |
| Electrical Functionality | At each temperature | 0.05\% |
| Parametric, DC | extreme. | 0.05\% |
| Mechanical |  |  |
| Critical | - | 0.01\% |
| Major | - | 0.28\% |

# Reliability of CMOS Microcircuits <br> PR-5 

## Introduction

With the entry into the integrated circuit marketplace of Complementary-Metal-Oxide Semiconductor (CMOS) technology, an electronic revolution comparable to that following the introduction of bipolar transistor technology was stimulated. The trend toward increased use of CMOS in industrial and consumer systems came about principally because of the unique properties associated with these devices. For example, P- and $N$-channel enhancement mode transistors are combined on the same chip, which makes possible highspeed operation, high noise immunity, and low stand-by power dissipation in the nanowatt range. Only one power supply is required, and the circuit is operated so that only one transistor is on at a time. Significant power is dissipated only during change of state. The combination of these advantages, coupled with extremely small device size and National's stable and reliable CMOS fabrication process, has contributed to certain unique applications which could not be handled by more conventional MOS technologies.

National Semiconductor first entered the MOS market in early 1968 by producing established P-channel metal gate product. By mid-1972, National had introduced its first CMOS product line. The salient points in the chronological history of CMOS logic at National are:

1. National introduces in early- 1972 the CD40xxA series as its first CMOS product line. These parts were designed as a second source to the RCA CMOS products.
2. By mid-1972, a second product line, the MM74Cxxx series, is introduced. These are proprietary CMOS parts which are pin and functional equivalents of many of the most popular devices in the 74xx TTL series.
3. CMOS logic is qualified by MIL-M-38510 Program in late 1975. This program is designed to standardize the integrated circuit industry and at the same time provide the customer with the highest possible quality level for the required application.
4. Significant improvements in the majority of the CD40xxA series result in the introduction of the CD40xxB series in mid-1976. Internal buffers, acting in most cases as a pair of inverters, are added to all outputs. This results in making the output drive (in both directions) a uniform and standard value which in turn makes rise and fall times more nearly identical.
5. In early 1977, National introduces its analog-to-digital (A-to-D) converters into the series: the ADC 08xx, a Single Chip Data Acquisition System; and the ADC 3xxx, a 31/2- to 33/4-digit Digital Volt Meter (DVM) chip.
6. In recognition of the necessity of CMOS logic product to withstand exposure to radiation in satellite systems and space vehicles, National in early 1977 introduces the industry's first complete line of radiationhardened devices. Both the traditional 40xx series and National's own TTL compatible MM74Cxx series can withstand radiation exposures of $10^{6}$ Rads.

And today, National Semiconductor offers a broad spectrum of CMOS logic devices:

- 20 in the CD 4000 A series
- 85 in the MM54C/74C series
- 67 in the CD4000B series
- 13 CD45XX series
- 5 A-to-D Converters
- 57 Radiation Hardened devices.

The report which follows describes National's quality and reliability program, including test-results data for National's integrated CMOS product in Epoxy B. The basic principles of CMOS will be presented, together with National's processing philosophy, production techniques, and the methods and programs now in place to assure the end product's quality and reliability.

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CMOS wafer fabrication is designed to produce reliable, high-performance devices which require minimum handling restrictions. At National Semiconductor, these objectives are achieved through the use of advanced materials, process innovations, and rigorous process controls.

The substrate material used in the CMOS process is [1-0.0]-orientation N-type silicon rather than the commonly selected [1-1-1]-orientation type. Coupled with controlled processing, this substrate permits the fabrication of MOS transistors with threshold voltages up to half as low as that produced on [1-1-1]-orientation silicon. Lower threshold voltages allow higher-speed circuit operation with lower supply voltages. In addition, the threshold voltage distribution from run to run is much tighter, so that long-term uniformity of device characteristics is assured.

The stability of CMOS characteristics depends directly on the level of contamination in the gate oxide. National's proprietary oxidation procedure and cleaning methods are capable of producing ultra-clean oxides. In order to ensure low levels of oxide contamination in production, capacitance-voltage (C-V) process controls have been installed.

All production oxidation and evaporation systems are monitored on a regular basis using the capacitance-voltage method. An MOS capacitor is fabricated and drifted under +15 V bias at $275^{\circ} \mathrm{C}$ for two minutes. The shift in the $\mathrm{C}-\mathrm{V}$ plot is a measure of the ionic contamination in the oxide under evaluation. This method is also used for investigations of process changes and innovations. These measurements assure rapid detection and correction of production process difficulties before contaminated material can leave the wafer processing area.

An additional check on stability is performed on completed wafers. Fields of $\pm 2 \times 10^{6} \mathrm{~V} / \mathrm{cm}$ are applied to $\mathrm{C}-\mathrm{V}$ test dots designed into the device die while the wafer is heated to $275^{\circ} \mathrm{C}$ for two minutes, then cooled to room temperature. The C-V shift is measured before and after heating for both bias conditions. The maximum permissible shift in threshold voltage is 0.40 V with typical shifts running less than 0.15 V .

Moreover, National's CMOS devices have a double input diode protection network designed to prevent catastrophic failures caused by positive- or negative-going voltage transients. This effective input protection network, coupled with excellent oxide integrity, reduces the handling restrictions required on CMOS devices. A detailed guide to the handling requirements of CMOS parts is given in the last section of this report.

The following is a pictorial representation of National's CMOS device fabrication. (Please note that the drawings are not to scale.)


Figure 1. Initial Oxidation, Thermally Grown Silicon Dioxide Layer on Silicon Substrate Surface


Figure 2. P-Mask \& Formation of P-Well Tub in which N-Channel Devices will be Located


Figure 3. P-Well Oxidation, Thermally Grown Silicon Dioxide Layer over P.Well Area


Figure 4. P+ Mask \& Formation of Low Resistance P+ Type Pockets in P-Well and N-Substrate


Figure 5. P+ Oxidation, Thermally Grown Silicon Dioxide Layer over P+ Type Pockets


Figure 6. $\mathbf{N +}$ Mask and Formation of Low Resistance $\mathbf{N}+$ Type Pockets in P-Well \& N-Substrate


Figure 8. Composite Mask \& Openings to $N$ and $P$ Channel Devices


Figure 9. Gate Oxidation, Thermally Grown Silicon Dioxide Layer over N and P Channel Devices


Figure 10. Contact Mask \& Openings to $\mathbf{N}$ and $P$ Channel Devices


Figure 11. Metallization, Metal Mask, Resulting in Gate Metal \& Metal Interconnects


Figure 12. Passivation Vapox, Deposited Silicon Dioxide over Entire Die Surface



Figure 13. Basic CMOS Inverter Circuit

Second in importance only to component design are the workmanship, tools, and internal procedures used in the manufacture of highly reliable CMOS microcircuits. No amount of testing and sorting will replace skill and extreme care in production processing.

The main task, therefore, is not only how to make a reliable product but also how to maintain the reliability level which is obtainable from a suitable design. The answer lies in meticulous control over production techniques and in painstaking process control checks and quality control gates after critical operations.

The following outline briefly describes the standard CMOS production process and indicates each of the steps in this flow at which process control and checking are undertaken by Quality Assurance engineers and technicians.

## 1. Incoming Raw Materials are Received

Silicon wafers, wires, frames, plastic, photo resist, chemicals, molding compounds, emulsion work plates, etc.

## Quality Assurance Incoming Inspection

The raw materials are purchased from a qualified vendor and must meet stringent material procurement specifications. Samples are inspected and tested to dimensional, physical, mechanical, chemical, and environmental specifications. Each vendor must maintain a continuous history of acceptable quality shipments in order to remain on National's list of qualified vendors.

## 2. Wafer Processing

All operations are carried out in closely monitored clean conditions. Material waiting for subsequent operations is stored under laminarflow hoods (Class 100, Federal Standard 209A). All wafers are visually inspected for defects under collimated light prior to initial oxidation. Wafers are rejected which fail to meet the criteria defined by written process specifications.

## Initial Oxidation

$5,000 \AA$ of silicon dioxide are thermally grown. An optical measurement of oxide thickness is made.
4. P-Mask

This masking step is used to form the P -well in which N -channel devices are to be located.

Optical inspection is made at 400X power for characteristics such as cleanliness, continuity, and definition. Precision optical-dimensional measurements using an image-shearing microscope are made to check the accuracy of device geometry.

## 5. Pre-Ion-Implant Oxidation

A thin layer of silicon dioxide is thermally grown. This oxidation is primarily done to improve the uniformity of the subsequent ion implantation.
6. Ion Implantation of CMOS P-Well

Ion implantation is inherently a low-temperature process offering excellent boron-impurity control of surface doping concentrations.

## Ion Implant P-Well Quality Control

The boron-ion concentration is checked by measuring V/I on a specially prepared N -type test wafer.

## Ion Implant P-Well Drive-in and Oxidation

A drive-in cycle including thermal annealing is followed by silicondioxide oxidation over the P -well.

P+Mask
The second mask provides source and drain regions for P-channel devices, substrate-to-ground diodes (guard bands), and $\mathrm{V}_{\mathrm{DD}}$ input diodes.

## Etch Inspect Quality Control

Optical and dimensional inspections as described after the first masking operation above are repeated.
9. $\mathbf{P}+$ Diffusion

All $P+$ regions are thermally doped followed by a drive-in and oxidation. Measurements are made to determine sheet resistance, junction depth, and field oxide thickness in the $P+$ source and drain diffused regions. Pre-deposition $\mathrm{V} / \mathrm{l}$ and oxidation thickness are held within $10 \%$ of design values, which results in tighter electrical distributions.

N+Mask
The third mask provides N -type source and drain regions in P -well for N -channel devices, channel guard bands, and $\mathrm{V}_{\mathrm{SS}}$ input diodes.

## Etch Inspect Quality Control

Optical and dimensional inspections (as previously described) are repeated.
$\mathbf{N}+$ Diffusion
Source and drain regions in P -well are thermally doped followed by a drive-in and oxidation. As with $\mathrm{P}+$ diffusion, measurements are made to determine sheet resistance, junction depth, and the field oxide thickness in the $\mathrm{N}+$ source and drain diffused regions. - Again, pre-deposition V/I and oxidation thickness are held within $10 \%$ of design value so as to have tighter electrical distributions.

## Composite Mask

The fourth mask opens the thermal oxide over the N - and P -channel gate regions in preparation for gate oxidation.

## Etch Inspect Quality Control

The same post-mask optical and dimensional inspections as described previously are repeated.

## 13. Gate Oxidation

A thin layer of silicon dioxide is thermally grown as drift-free gate electrical material over the N - and P -channel gate regions.

## Gate Oxidation Quality Control

Interferometer measurements are made of the oxide thickness on specially prepared test wafers. An indirect evaluation of aluminum evaporation and of the quality of the cleaning process is obtained as a consequence of a control loop procedure.
14. Metal Contact Mask

The fifth mask opens the thermal oxide over the source and drain tubs of N - and P -channel devices as well as over $\mathrm{N}+$ and $\mathrm{P}+$ contacts.

## Etch Inspect Quality Control

The same optical and dimensional inspections as performed before are repeated.
15. Metallization

A thin film of aluminum is sputtered in a vacuum over the entire surface of the wafer.

## Metallization Quality Control

Metallization thickness is controlled in each production run by sectioning, the use of interferometers, etc. A dynamic capacitance voltage plot is taken to verify the absence of sodium contamination in the metallization process.
16. Metal Mask

The sixth mask is used to form aluminum interconnection patterns, contacts, and bonding gates.

## Etch Inspect Quality Control

Previously described optical and dimensional inspections are repeated.
17. Alloy

Aluminum metal interconnections to device contact regions are alloyed.
18. Passivation Vapox

A chemically-vapor-deposited glass (vapox) provides metal scratch protection and getters positive mobile ionic charges.

## Passivation Vapox Quality Control

The percentage of phosphorous concentration in the vapox is measured by diffusion from the deposited oxide source, and doublechecked by analysis of the diffused layer surface concentration on test wafers using X-ray fluorescence techniques. Also measured are defect density and etch rate.

The seventh mask opens the vapox over the aluminum bonding areas.

## Etch Inspect Quality Control

Once more, an optical etch inspection is made at 400X power to check on cleanliness, continuity, and definition. Precision opticaldimensional measurements using an image-shearing microscope are made to determine the accuracy of device geometry.

## Electrical Test Quality Assurance

Together with the C-V test, measurements are made of electrical parameters sensitive to slight process variations, including transistor threshold, current gain, junction reverse-breakdown voltages, and diffused region sheet resistivities. MOS capacitors on test arrays are measured for fast surface-state density ( $Q_{S S}$ ), mobile ionic contamination $\left(Q_{0}\right)$, and the thickness of gate oxide dielectric. These data are used to maintain tight process controls.
20. Dynamic Capacitance Voltage Plot

A positive 15 volts are applied to a $\mathrm{C}-\mathrm{V}$ dot designed into the device die while the wafer is heated to $275^{\circ} \mathrm{C}$, held at temperature for two minutes, then cooled to room temperature. C-V plots of threshold voltage on N - and P -channels are made before and after heating to determine $V_{t}$.
21. Product Wafer Probe

Each die receives a complete functional test to all conditions and parameters specified on the device data sheet. Supply voltages are applied over the guaranteed ranges. Dice failing to meet any of these tests are inked for subsequent removal.

## Epoxy B Package Processing Flow



## Sorted Wafers are Received

All dice on wafers have been $100 \%$ electronically tested.
Electrical rejects are marked with an ink spot.
Diamond-Saw, Break, and Plate Dice
Inked dice are removed.

## 2. Optical Die Sort

$100 \%$ optical microscope inspection at 100 X to remove potentially unreliable dice.
Lead
Quality Control Surveillance Begins
Frame
Verification is made that the optical die sort was
performed according to written specifications.

## 3. Die Attach

Polymer attachment of die to lead frame.

## Quality Control Surveillance

Gold Wire

Molding
Compound

Verification is made that the die-attach operation was performed according to written specifications.

## 4. Lead Bond

Thermocompression ball-bonding of gold wire to die and lead frame.

## Quality Control Surveillance

Several times each shift, samples are checked from each machine and from each operator's work.

## Quality Assurance Lead Bond Pull Test

Samples by lot from each operator are checked a minimum of twice per shift. All bonds are pulled to destruction. The force required to break the bond, and the location of the break, are recorded for processcontrol purposes.

## 5. Pre-Mold Optical Sort

$100 \%$ optical microscope inspection at 30X for assembly defects. Devices are inspected for wafer processing anomalies, assembly work damage, completeness, and accuracy of assembly.

## Quality ControI Surveillance

Samples of each optical sorter's work are inspected to criteria which meet or exceed the applicable requirements of Mil-Std-883B, Method 2010.
6. Mold and Cure

Thermosetting plastic is transfer molded around the completed assembly. The plastic is then cured to insure mechanical and chemical stability.


## 7. Trim and Form Leads

Frame supports are removed and leads formed to desired configuration.
8. Tin Dip Leads (Non pre-plated frames only)

Frames which have not been plated prior to die attach (Step 3) are hot-solder dipped to provide protection against corrosion and for excellent solderability.

## Quality Control Surveillance

Visual and mechanical quality are continuously monitored.

## 9. Mark Package

Devices are marked with National's part number, a date code (signifying mold week), and the National logo.

## Clip Rails

Lead-frame rails are removed, leaving finished devices ready for test
11. Electrical Test
$100 \%$ electrical test on all data-sheet parameters.

## Quality Assurance Acceptance

Each lot of finished devices is sample inspected and tested by Quality Assurance Inspectors for compliance with specifications.
12. Pack and Ship

Each shipment is inspected by Quality Assurance to be sure that the right devices are going in the right quantity to the right customer.

## Environmental and Life Test Data of CD40XXC and MM74CXXM

As was noted in the Introduction, CMOS serves as an ideal solution for industrial and consumer (and aerospace) systems which cannot be handled by more conventional MOS technologies. In these critical applications, reliability is of major importance. The data which follow are the summations of 1979-1980 reliability tests conducted on commercial CMOS devices in Epoxy B.

## Criteria

Two failure categories are considered:

1. Degradation - Devices which are still able to perform logical functions, but whose electrical parameters have drifted beyond published specifications.
2. Catastrophic - Devices with opens or shorts, or those which fail to perform logical functions because of increased leakage or a shift in any other electrical parameter.

## Temperature Cycle Test，Results

The air－to－air temperature cycle is conducted in accordance with Mil－Std－883B， Method 1010.2 ，from $0^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}, 10$ minutes dwell time at temperature extremes， 2 second transfer time， 20 minutes per cycle．

|  | Sample | Failures at： |  |
| :---: | :---: | :---: | :---: |
| Lots | Size | $\mathbf{1 , 0 0 0}$ Cycles | $\mathbf{2 , 0 0 0}$ Cycles |
| 12 | 2,500 | 0 | 1 |

## Thermal Shock

The liquid－to－liquid thermal shock test is conducted in accordance with Mil－Std－883B，Method 1011．2，Test Condition C，$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ ．

| Lots | Sample <br> Size | Failures at： |  |
| :---: | :---: | :---: | :---: |
| 50 Cycles | 100 Cycles |  |  |
| 25 | 450 | 0 | 0 |

## Autoclave（Pressure Pot）

The pressure pot test is conducted in a steam autoclave at $121^{\circ} \mathrm{C}, 15 \mathrm{psig}$ ，and $100 \%$ relative humidity for 96 hours．

| Lots | Sample <br> Size | No． <br> Fail |
| :---: | :---: | :---: |
| 52 | 1,200 | 5 |

## High Temperature Storage

The high temperature storage test is conducted in accordance with Mil－Std－883B，Method 1008.1 ，Test Condition C，at $150^{\circ} \mathrm{C}$ ．

| Lots | Sample <br> Size | $\mathbf{1 6 8 ~ H r s}$ | Failures at： <br> $\mathbf{5 0 0} \mathbf{H r s}$ | $\mathbf{1 0 0 0} \mathbf{H r s}$ |
| :---: | :---: | :---: | :---: | :---: |
| 9 | 210 | 0 | 0 | 1 |

## Moisture Resistance

$85^{\circ} \mathrm{C}, 85 \%$ relative humidity，static life conditions，biased with rated voltage．

| Lots | Sample <br> Size | $\mathbf{1 6 8}$ Hrs | Failures＊at： <br> $\mathbf{5 0 0} \mathbf{~ H r s}$ | $\mathbf{1 0 0 0} \mathbf{H r s}$ |
| :---: | :---: | :---: | :---: | :---: |
| 40 | 1,279 | 2 | 18 | 5 |

[^30]

Figure 14. Failure Rate at $85^{\circ} \mathrm{C} / 85 \% \mathrm{RH}$
High Temperature Operating Life ( $125^{\circ} \mathrm{C}$, Bias $=+\mathbf{1 5 V}$ )

| Sample <br> Size | $\mathbf{1 6 8 ~ H r s}$ | Failures at: <br> $\mathbf{5 0 0 ~ H r s}$ | $\mathbf{1 , 0 0 0} \mathbf{~ H r s}$ | \% Fail// <br> $\mathbf{1 , 0 0 0 ~ H r s . ~}$ | MTBF <br> Hours |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 40 | 1,472 | 5 | 4 | 8 | $1.2 \%$ |
| Total Test Hours: $1,472,000$ |  |  |  |  |  |
| Equivalent Hours at $70^{\circ} \mathrm{C}:$ | $125 \times 10^{6} \dagger$ |  | $0.86 \times 10^{5}$ |  |  |
| Equivalent Hours at $45^{\circ} \mathrm{C}:$ | $1562 \times 10^{6} \dagger$ |  | $0.014 \%$ |  |  |

$\dagger$ Activation Energy $=0.7 \mathrm{eV}$

## Notes:

1. The failures are data sheet limit failures.
2. Failure rate $(\lambda)$, or predicted percent failure per 1,000 hours, is at $60 \%$ Confidence Level.
3. Failure rate percentage is the inverse of Mean Time Between Failures (MTBF).
4. Failure rates derived for $70^{\circ} \mathrm{C}$ and $45^{\circ} \mathrm{C}$ were obtained using acceleration factors related to actual test ambient temperatures.

The following figure shows the Field Failure Rate predicted for CMOS devices when operated at $70^{\circ} \mathrm{C}$. The Infant Mortality section of the curve is shaded because Infant Mortality is strongly influenced by numerous variables such as handling, system-induced voltage transients, temperature, environment, mechanical stress, etc., and therefore varies widely.


Figure 15. Field Failure Rate at $70^{\circ} \mathrm{C}$

The single，most prevalent cause of＂Infant Mortality＂field failures in CMOS microcircuits is gate oxide damage．This can result from any transient voltage condition－electrostatic discharge（ESD），electrical noise，inductive spikes， etc．Effective input protection circuitry（see page 2 for further discussion）， such as that used on National＇s CMOS chips，can provide effective protection provided the gate oxide itself is inherently reliable．National＇s standard gate oxide is designed to withstand 80 volts．As in any process，there is always some deviation from the normal．Nevertheless，it has been proven by National Reliability Engineering analyses that most devices which fail because of gate oxide damage actually have inferior gate oxide to start with－or an oxide which will rupture at voltages considerably below the＂ 3 sigma limit＂of the normal distribution．

National has improved its gate oxidation process in the areas of cleaning， masking，and controls to the point where the＂ 3 sigma limit＂is as small as possible．This guarantees that the inherent reliability of the process is preserved．Thus，the chance for failure caused by gate oxide rupture is drastically reduced．Translated to field performance，this means an absolute minimum of＂Infant Mortality＂failures in the operation of CMOS devices in their end－use environment．


Diode Breakdown
$\mathrm{D}_{1}=25$ Volts
$\mathrm{D}_{2}=60$ Volts
$D_{3}=100$ Volts
＊These are Intrinsic Diodes

## Introduction

All CMOS low-threshold devices are susceptible to damage by the electrostatic discharge (ESD) of energy through the devices. This is because the gate oxide thickness of such devices is in the range of $1,000 \AA$ to $1,100 \AA$, which limits the maximum voltage that can be applied (to the input of the device) to 80 V with a reasonable safety factor. (For a fuller description of ESD and its possible latent effects on microcircuits, see National Semiconductor's Reliability Physics Brief, RPB-02, July 1978, and Reliability Physics Brief, RPB-07, January 1980.) Although all CMOS devices have input protection networks which are effective in a large number of device-handling situations, they are not effective in $100 \%$ of the cases (please refer to specific devices in National's CMOS Data Book).

In order to be totally safe, proper handling procedures must be used to eliminate damage and subsequent yield loss caused by static electrical charges. It is the purpose of this application guide to outline proper handling procedures for CMOS devices.

## General Handling Procedures

1. The leads of CMOS devices should be in contact with conductive material to avoid build-up of static charge. Containers used for transporting or storing CMOS components should be made of such material or lined with anti-static material. Rails for handling and shipping MOS devices should be made of electrically conductive material or be made static-free by an appropriate surface coating. In no case should CMOS devices be inserted into polystyrene foam or other high-dielectric materials. Any surface coating which is not at ground potential should not come in direct contact with device pins.
2. Devices should be packed in conductive containers, rails, or envelopes for storing. In addition, devices should be kept at ground potential and should never come in contact with non-conductive plastics.
3. All electrical equipment should be hard-wired to ground. Soldering iron tips, metal parts of fixtures and tools, and all handling systems should be grounded.

## Cleaning

1. Devices should be cleaned by a solvent which will assure complete removal of foreign matter, flux, residual matter, etc., from the exterior of the package.
2. A static-neutralizing ion blower should be used when manually cleaning devices or sub-assemblies with brushes.
3. All automatic cleaning should be grounded.
4. All cleaning baskets should be grounded.

## Assembly

1. Sub-assembled modules and printed circuit boards should be manufactured and handled using the same procedures as those described above for individual CMOS devices.
2. CMOS parts should be the last to be inserted into printed circuit boards or systems so as to avoid overhandling.
3. Circuit boards containing CMOS devices which are being transported between work stations and test areas should be contained in anti-static material or have all board terminals shorted together using a conductive shorting bar. Only handling trays of conductive material should be used.
4. All automatic insertion equipment, solder machines, metallic parts of conveyor systems, and soldering irons should be grounded.

Note: These precautions should be taken until the sub-assembly is inserted into the complete system in which the proper voltages are applied. Sub-assemblies should never be constructed, fixtured, stored or transported in polystyrene or any other high-dielectric materials.

## General Operating Procedures

The National CMOS product line is comprised of many different device types for a variety of applications. The following operating procedures apply in a general sense to all CMOS devices, but reference to device specification sheets is still necessary to assure correct operating values.
A. Before making any physical connections or applying any external signal sources, be sure that all power supplies are off. Be sure, also, to observe proper static ground conditions.
B. Power supplies should be turned up slowly to the necessary voltages so as to avoid rapid supply changes.
C. After power supplies have been turned on, apply external input signals.

Note: Failure to perform the power-on procedure in this order can result in damaged CMOS circuitry.
D. To power down, remove input signals first, then turn power supplies off slowly.
E. If CMOS devices are operated at an elevated environmental temperature, allow devices to reach room temperature before they are powered down.
F. Do not leave inputs to any CMOS device unused. For NAND gates the unused inputs should be tied to $\mathrm{V}_{\text {DD }}$; unused inputs to NOR gates should be tied to ground. Tying unused inputs to used inputs will result in an increase in source current of a NAND gate, and in an increase in sink current of a NOR gate.

## Testing

1. Use grounded metallic fixtures where possible. Any surface that is not at ground potential should not come into direct contact with device pins.
2. Use a static-neutralizing ion air blower when running automatic handlers. Use conductive handling trays when transferring devices.
3. Do not insert devices or boards with power turned on.
4. Ensure that $A C$ signals do not cause excessive current leakage.

## Electrical Failure Modes Caused by Improper Handling

If proper handling techniques are not followed, it is likely that the generation of static electrical discharges will damage the CMOS devices, resulting in inoperable or degraded parts. Typical failure modes are:

1. Shorted or open gates;
2. Shorted or leaky input protection diodes;
3. Open metal paths in the device input circuitry; and
4. Degraded device characteristics, especially g (mutual transconductance or "gain").

The presence of these failure modes can be detected easily using a transistor curve tracer.

## Section 8

## Application Notes

## CMOS，the Ideal Logic Family

## INTRODUCTION

Let＇s talk about the characteristics of an ideal logic family．It should dissipate no power，have zero propagation delay，controlled rise and fall times， and have noise immunity equal to $50 \%$ of the logic swing．
Well，that ideal logic family is here－almost． The properties of CMOS（complementary MOS） begin to approach these ideal characteristics．
First，CMOS dissipates low power．Typically，the static power dissipation is 10 nW per gate which is due to the flow of leakage currents．The active power depends on power supply voltage，frequency， output load and input rise time，but typically，gate dissipation at 1 MHz with a 50 pF load is less than 10 mW ．

Second，the propagation delays through CMOS are short，though not quite zero．Depending on power supply voltage，the delay through a typical gate is on the order of 25 to 50 ns ．

Third，rise and fall times are controlled，tending to be ramps rather than step functions．Typically， rise and fall times tend to be 20 to $40 \%$ longer than the propagation delays．
Last，but not least，the noise immunity approaches $50 \%$ ，being typically $45 \%$ of the full logic swing．

Besides the fact that it approaches the characteris－ tics of an ideal logic family and besides the obvious low power battery applications，why should de－ signers choose CMOS for new systems？The answer is cost．

On a component basis，CMOS is still more expen－ sive than TTL．However，system level cost may be

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TABLE 1．Comparison of 54L／74L Low Power TTL and 54C／74C CMOS Port Parameters．

| FAMILY | V cc | $\begin{aligned} & V_{\mathrm{IL}} \\ & \text { MAX } \end{aligned}$ | $\operatorname{IIL}_{\text {MAX }}$ | $\begin{aligned} & V_{I H} \\ & \mathrm{MIN} \end{aligned}$ | $\begin{aligned} & 1_{1 \mathrm{H}} \\ & 2.4 \mathrm{~V} \end{aligned}$ | $\mathrm{V}_{\mathrm{OL}}$ MAX | Iol | $\mathrm{V}_{\mathrm{OH}}$ <br> MIN | $\mathrm{IOH}^{\text {O}}$ | $\begin{aligned} & \mathbf{t}_{\text {pdo }} \\ & \text { TYP } \end{aligned}$ | $\begin{aligned} & \mathbf{t}_{\mathrm{pd1}} \\ & \mathrm{~T}_{\mathrm{Y}} \mathrm{P} \end{aligned}$ | PDISS／GATE STATIC | Potss／GATE <br> $1 \mathrm{MHz}, 50 \mathrm{pF}$ LOAD |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 54L／74L | 5 | 0.7 | 0.18 mA | 2.0 | $10 \mu \mathrm{~A}$ | 0.3 | 2.0 mA | 2.4 | $100 \mu \mathrm{~A}$ | 31 | 35 | 1 mW | 2.25 mW |
| 54C／74C | 5. | 0.8 | － | 3.5 | － | 0.4 | ${ }^{*} 360 \mu \mathrm{~A}$ | 24 | $\cdot 100 \mu \mathrm{~A}$ | 60 | 45 | 0.00001 mW | 1.25 mW |
| 54C／74C | 10 | 2.0 | － | 8.0 | － | 10 | ＊ $10 \mu \mathrm{~A}$ | 9.0 | $\cdots 10 \mu \mathrm{~A}$ | 25 | 30 | 0.00003 mW | 5 mW |

[^31]lower．The power supplies in a CMOS system will be cheaper since they can be made smaller and with less regulation．Because of lower currents，the power supply distribution system can be simpler and therefore，cheaper．Fans and other cooling equipment are not needed due to the lower dissi－ pation．Because of longer rise and fall times，the transmission of digital signals becomes simpler making transmission techniques less expensive． Finally，there is no technical reason why CMOS prices cannot approach present day TTL prices as sales volume and manufacturing experience in－ crease．So，an engineer about to start a new design should compare the system level cost of using CMOS or some other logic family．He may find that，even at today＇s prices，CMOS is the most economical choice．

National is building two lines of CMOS．The first is a number of parts of the CD4000A series．The second is the $54 \mathrm{C} / 74 \mathrm{C}$ series which National introduced and which will become the industry standard in the near future．

The 54C／74C line consists of CMOS parts which are pin and functional equivalents of many of the most popular parts in the 7400 TTL series．This line is typically $50 \%$ faster than the 4000A series and sinks $50 \%$ more current．For ease of design，it is spec＇d at TTL levels as well as CMOS levels，and there are two temperature ranges available： 54 C ， $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ or $74 \mathrm{C},-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ ．Table 1 compares the port parameters of the $54 \mathrm{C} / 74 \mathrm{C}$ CMOS line to those of the $54 \mathrm{~L} / 74 \mathrm{~L}$ low power TTL line．

## CHARACTERISTICS OF CMOS

The aim of this section is to give the system designer not familiar with CMOS, a good feel for how it works and how it behaves in a system. Much has been written about MOS devices in general. Therefore, we will not discuss the design and fabrication of CMOS transistors and circuits.

The basic CMOS circuit is the inverter shown in Figure 2-1. It consists of two MOS enhancement mode transistors, the upper a P-channel type, the lower an N -channel type.


FIGURE 2-1. Basic CMOS Inverter.
The power supplies for CMOS are called $V_{D D}$ and $\mathrm{V}_{\mathrm{SS}}$, or $\mathrm{V}_{\mathrm{CC}}$ and Ground depending on the manufacturer. $V_{D D}$ and $V_{S S}$ are carryovers from conventional MOS circuits and stand for the drain and source supplies. These do not apply directly to CMOS since both supplies are really source supplies. $V_{C C}$ and Ground are carryovers from TTL logic and that nomeclature has been retained with the introduction of the $54 \mathrm{C} / 74 \mathrm{C}$ line of CMOS. $V_{\text {CC }}$ and Ground is the nomenclature we shall use throughout this paper.

The logic levels in a CMOS system are $\mathrm{V}_{\mathrm{cc}}$ (logic " 1 ") and Ground (logic " 0 "). Since "on" MOS transistor has virtually no voltage drop across it if there is no current flowing through it, and since the input impedance to CMOS device is so high (the input characteristic of an MOS transistor is essentially capacitive, looking like a $10^{12} \Omega$ resistor shunted by a 5 pF capacitor), the logic levels seen in a CMOS system will be essentially equal to the power supplies.

Now let's look at the characteristic curves of MOS transistors to get an idea of how rise and fall times, propagation delays and power dissipation will vary with power supply voltage and capacitive loading. Figure $2-2$ shows the characteristic curves of N -channel and P -channel enhancement mode transistors.

There are a number of important observations to be made from these curves. Refer to the curve of $V_{G S}=15 \mathrm{~V}$ (Gate to Source Voltage) for the N -channel transistor. Note that for a constant drive voltage $\mathrm{V}_{\mathrm{GS}}$, the transistor behaves like a current source for $\mathrm{V}_{\mathrm{DS}}$ 's (Drain to Source Voltage) greater than $V_{G S}-V_{T}\left(V_{T}\right.$ is the threshold
voltage of an MOS transistor). For $\mathrm{V}_{\mathrm{DS}}$ 's below $\mathrm{V}_{\mathrm{GS}}-\mathrm{V}_{\mathrm{T}}$, the transistor behaves essentially like a resistor. Note also that for lower $\mathrm{V}_{\mathrm{Gs}}$ 's, there are similar curves except that the magnitude of the $I_{D S}$ 's are significantly smaller and that in fact, $I_{D S}$ increases approximately as the square of increasing $\mathrm{V}_{\mathrm{Gs}}$. The P-channel transistor exhibits essentially identical, but complemented, characteristics.



FIGURE 2-2. Logical "1" Output Voltage vs Source Current.

If we try to drive a capacitive load with these devices, we can see that the initial voltage change across the load will be ramp-like due to the current source characteristic follówed by a rounding off due to the resistive characteristic dominating as $\mathrm{V}_{\mathrm{DS}}$ approaches zero. Referring this to our basic CMOS inverter in Figure 2-1, as $\mathrm{V}_{\mathrm{DS}}$ approaches zero, $V_{\text {OUt }}$ will approach $\mathrm{V}_{\mathrm{CC}}$ or Ground depending on whether the P -channel or N -channel transistor is conducting.

Now if we increase $\mathrm{V}_{\mathrm{CC}}$ and, therefore, $\mathrm{V}_{\mathrm{GS}}$ the inverter must drive the capacitor through a larger voltage swing. However, for this same voltage increase, the drive capability ( $I_{\text {DS }}$ ) has increased roughly as the square of $\mathrm{V}_{\mathrm{Gs}}$ and, therefore, the rise times and the propagation delays through the inverter as measured in Figure 2-3 have decreased.

So, we can see that for a given design, and therefore fixed capacitive load, increasing the power supply voltage will increase the speed of the system.

Increasing $\mathrm{V}_{\mathrm{cc}}$ increases speed but it also increases power dissipation. This is true for two reasons. First, $\mathrm{CV}^{2} \mathrm{f}$ power increases. This is the power dissipated in a CMOS circuit, or any other circuit for that matter, when driving a capacitive load.


FIGURE 2-3. Rise and Fall Times and Propagation Delays as Measured in a CMOS System.

For a given capacitive load and switching frequency, power dissipation increases as the square of the voltage change across the load.

The second reason is that the VI power dissipated in the CMOS circuit increases with $V_{c c}$ (for $V_{c c}$ 's $>2 \mathrm{~V}_{\mathrm{T}}$ ). Each time the circuit switches, a current momentarily flows from $V_{c c}$ to Ground through both output transistors. Since the threshold voltages of the transistors do not change with increasing $\mathrm{V}_{\mathrm{CC}}$, the input voltage range through which the upper and lower transistors are conducting simultaneously increases as $V_{\text {cc }}$ increases. At the same time, the higher $\mathrm{V}_{\mathrm{CC}}$ provides higher $\mathrm{V}_{\mathrm{GS}}$ voltages which also increase the magnitude of the $I_{D S}$ currents. Incidently, if the rise time of the input' signal was zero, there would be no current flow from $V_{c c}$ to Ground through the circuit. This current flows because the input signal has a finite rise time and, therefore, the input voltage spends a finite amount of time passing through the region where both transistors conduct simultaneously. Obviously, input rise and fall times should be kept to a minimum to minimize VI power dissipation.

Let's look at the transfer characteristics, Figure 2-4, as they vary with $\mathrm{V}_{\mathrm{cc}}$. For the purposes of this discussion we will assume that both transistors in our basic inverter have identical but complementary characteristics and threshold voltages. Assume the threshold voltages, $\mathrm{V}_{\mathrm{T}}$, to be 2 V . If $\mathrm{V}_{\mathrm{cc}}$ is less than the threshold voltage of 2 V , neither transistor can ever be turned on and the circuit cannot operate. If $\mathrm{V}_{\mathrm{CC}}$ is equal to the threshold voltage exactly then we are on the curve Figure 2-4a. We appear to have $100 \%$ hysteresis. However, it is not truly hysteresis since both output transistors are off and the output voltage is being held on the gate capacitances of succeeding circuits. If $\mathrm{V}_{\mathrm{CC}}$ is somewhere between one and two threshold voltages (Figure 2-4b), then we have diminishing amounts of "hysteresis" as we approach $V_{C C}$ equal to $2 \mathrm{~V}_{\mathrm{T}}$ (Figure $2-4 \mathrm{c}$ ). At $\mathrm{V}_{\mathrm{Cc}}$ equal to two thresholds we have no "hysteresis" and no current flow through both the upper and lower transistors during switching. As $V_{c c}$ exceeds two thresholds the
transfer curves begin to round off (Figure 2-4d). As $V_{\text {IN }}$ passes through the region where both transistors are conducting, the currents flowing through the transistors cause voltage drops across them giving the rounded characteristic.


FIGURE 2-4. Transfer Characteristics vs $V_{C C}$.

Considering the subject of noise in a CMOS system, we must discuss at least two specs: noise immunity and noise margin.

National's CMOS circuits have a typical noise immunity of $0.45 \mathrm{~V}_{\mathrm{cc}}$. This means that a spurious input, which is $0.45 \mathrm{~V}_{\mathrm{Cc}}$ or less away from $\mathrm{V}_{\mathrm{CC}}$ or Ground typically will not propagate through the system as an erroneous logic level. This does not mean that no signal at all will appear at the output of the first circuit. In fact, there will be an output signal as a result of the spurious input, but it will be reduced in amplitude. As this signal propagates through the system, it will be attenuated even more by each circuit it passes through until it finally disappears. Typically, it will not change any signal to the opposite logic level. In a typical flip flop, a $0.45 \mathrm{~V}_{\mathrm{cc}}$ spurious pulse on the clock line would not cause the flop to change state.

National also guarantees that its CMOS circuits have a 1V DC noise margin over the full power supply range and temperature range and with any combination of inputs. This is simply a variation of the noise immunity spec only now a specific set of input and output voltages have been selected and guaranteed. Stated verbally, the spec says that for the output of a circuit to be within $0.1 \mathrm{~V}_{\mathrm{cc}}$ volts of a proper logic level ( $\mathrm{V}_{\mathrm{Cc}}$ or Ground), the input
can be as much as $0.1 \mathrm{~V}_{\mathrm{cc}}$ plus 1 V away from power supply rail. Shown graphically we have:


FIGURE 2-5. Guaranteed CMOS DC Margin Over Temperature as a Function of $\mathrm{V}_{\mathrm{CC}}$. CMOS Guarantees 1V.

This is similar in nature to the standard TTL noise margin spec which is 0.4 V .


FIGURE 2.6. Guaranteed TTL DC Margin Over Temperature as a Function of $V_{\text {CC }}$. TTL Guarantees 0.4 V .

For a complete picture of $\mathrm{V}_{\text {OUT }}$ vs $\mathrm{V}_{\text {IN }}$ refer to the transfer characteristic curves in Figure 2-4.

## SYSTEM CONSIDERATIONS

This section describes how to handle many of the situations that arise in normal system design such as unused inputs, paralleling circuits for extra drive, data bussing, power considerations and interfaces to other logic families.

Unused inputs: simply stated, unused inputs should not be left open. Because of the very high impedance $\left(\sim 10^{12} \Omega\right)$, a floating input may drift back and forth between a " 0 " and " 1 " creating some very intriguing system problems. All unused inputs should be tied to $\mathrm{V}_{\mathrm{Cc}}$, Ground or another used input. The choice is not completely arbitrary, however, since there will be an effect on the output drive capability of the circuit in question. Take, for example, a four input NAND gate being used as a two input gate. The internal structure is shown in Figure 3-1. Let inputs $A \& B$ be the unused inputs.

If we were going to tie the unused inputs to a logic level, inputs A \& B would have to be tied to $V_{\mathrm{cc}}$ to enable the other inputs to function. That would turn on the lower $A$ and $B$ transistors and turn off the upper A and B transistors. At most, only two of the upper transistors could ever be turned on. However, if inputs $A$ and $B$ were tied to input $C$, the input capacitance would triple, but each time C went low, the upper A, B and C transistors would turn on, tripling the available source current. If input $D$ was low also, all four of the upper transistors would be on.


FIGURE 3-1. MM74C20 Four Input NAND Gate.
So, tying unused NAND gate inputs to $V_{c c}$ (Ground for NOR gates) will enable them, but tying unused inputs to other used inputs guarantees an increase in source current in the case of NAND gates (sink current in the case of NOR gates). There is no increase in drive possible through the series transistors. By using this approach, a multiple input gate could be used to drive a heavy current load such as a lamp or a relay.

Parallel gates: depending on the type of gate, tying inputs together guarantees an increase in either source or sink current but not both. To guarantee an increase in both currents, a number of gates must be paralleled as in Figure 3-2. This insures that there are a number of parallel combinations of the series string of transistors (Figure 3-1), thereby increasing drive in that direction also.


FIGURE 3-2. Paralleling Gates or Inverters Increases Output Drive in Both Directions.

Data bussing: there are essentially two ways to do this. First, connect ordinary CMOS parts to a bus using transfer gates (part no. CD4016C). Second,
and the preferred way，is to use parts specifically designed with a CMOS equivalent of a TRI－STATE ${ }^{\circledR}$ output．

Power supply filtering：since CMOS can operate over a large range of power supply voltages（ 3 V to 15 V ），the filtering necessary is minimal．The minimum power supply voltage required will be determined by the maximum frequency of opera－ tion of the fastest element in the system（usually only a very small portion of any system operates at maximum frequency）．The filtering should be designed to keep the power supply voltage some－ where between this minimum voltage and the maximum rated voltage the parts can tolerate． However，if power dissipation is to be kept to a minimum，the power supply voltage should be kept as low as possible while still meeting all speed requirements．

Minimizing system power dissipation：to minimize power consumption in a given system，it should be run at the minimum speed to do the job with the lowest possible power supply voltage．AC and DC transient power consumption both increase with frequency and power supply voltage．The AC power is described as $C V^{2} f$ power．This is the power dissipated in a driver driving a capacitive load．Obviously，AC power consumption increases directly with frequency and as the square of the power supply．It also increases with capacitive load， but this is usually defined by the system and is not alterable．The DC power is the VI power dissipated during switching．In any CMOS device during switching，there is a momentary current path from the power supply to ground，（when $\mathrm{V}_{\mathrm{Cc}}>2 \mathrm{~V}_{\mathrm{T}}$ ） Figure 3－3．


VI POWER IS GIVEN BY：
$P_{V I}=V_{C C} \times \frac{1}{2} I_{\text {MAX }} \times$ RISE TIME TO PERIOD RATIO
$\underset{\text { PISE TIME TO }}{\text { PERIOD RATIO }}=\frac{V_{C C}-2 V_{T}}{V_{C C}} \times \frac{t_{\text {RISE }}+t_{\text {FALL }}}{t_{\text {TOTAL }}}$
WHERE $\frac{1}{t_{\text {TOTAL }}}=$ FREQUENCY
$P_{V_{V I}}=1 / 2\left(V_{C C}-2 V_{T}\right) I_{C C}$ MAX $\left(t_{\text {RISE }} * t_{\text {FALLL }}\right)$ FREQ．
FIGURE 3－3．DC Transient Power．

The maximum amplitude of the current is a rapidly increasing function of the input voltage which in turn is a direct function of the power supply， voltage．See Figure 2－4d．

The actual amount of VI power dissipated by the system is determined by three things：power supply voltage，frequency and input signal rise time．A very important factor is the input rise time．If the
rise time is long，power dissipation increases since the current path is established for the entire period that the input signal is passing through the region between the threshold voltages of the upper and lower transistors．Theoretically，if the rise time were zero，no current path would be established and the VI power would be zero．However，with a finite rise time there is always some current flow and this current flow increases rapidly with power supply voltage．

Just a thought about rise time and power dissipa－ tion．If a circuit is used to drive many loads，its output rise time will suffer．This will result in an increase in VI power dissipation in every device being driven by that circuit（but not in the drive circuit itself）．If power consumption is critical，it may be necessary to improve the rise time of that circuit by buffering or by dividing the loads in order to reduce overall power consumption．

So，to summarize the effects of power supply voltage，input voltage，input rise time and output load capacitance on system power dissipation，we can say the following：

1．Power supply voltage： $\mathrm{CV}^{2} \mathrm{f}$ power dissipation increases as the square of power supply voltage． VI power dissipation increases approximately as the square of the power supply voltage．

2．Input voltage level：VI power dissipation in－ creases if the input voltage lies somewhere between Ground plus a threshold voltage and $V_{\text {cc }}$ minus a threshold voltage．The highest power dissipation occurs when $\mathrm{V}_{\text {IN }}$ is at $1 / 2$ $\mathrm{V}_{\mathrm{Cc}} . \mathrm{CV}^{2} \mathrm{f}$ dissipation is unaffected．

3．Input rise time：VI power dissipation increases with longer rise times since the DC current path through the device is established for a longer period．The $\mathrm{CV}^{2} \mathrm{f}$ power is unaffected by slow input rise times．
4．Output load capacitance：the $\mathrm{CV}^{2} \mathrm{f}$ power dissi－ pated in a circuit increases directly with load capacitance．VI power in a circuit is unaffected by its output load capacitance．However，in－ creasing output load capacitance will slow down the output rise time of a circuit which in turn will affect the VI power dissipation in the devices it is driving．

## INTERFACES TO OTHER LOGIC TYPES

There are two main ideas behind all of the follow－ ing interfaces to CMOS．First，CMOS outputs should satisfy the current and voltage requirements of the other family＇s inputs．Second，and probably most important，the other family＇s outputs should swing as near as possible to the full voltage range of the CMOS power supplies．

P－Channel MOS：there are a number of things to watch for when interfacing CMOS and P－MOS．The first is the power supply set．Most of the more popular P－MOS parts are specified with 17 to 24 V power supplies while the maximum power supply voltage for CMOS is 15 V ．Another problem
is that unlike CMOS, the output swing of a pushpull P-MOS output is significantly less than the power supply voltage across it. P-MOS swings from very close to its more positive supply ( $\mathrm{V}_{\mathrm{SS}}$ ) to quite a few volts above its more negative supply $\left(V_{D D}\right)$. So, even if P-MOS uses a 15 V or lower power supply set, its output swing will not go low enough for a reliable interface to CMOS. There are a number of ways to solve this problem depending on the configuration of the system. We will discuss two solutions for systems that are built totally with MOS and one solution for systems that include bipolar logic.


FIGURE 3-4. A One Power Supply System Built Entirely of CMOS and P-MOS.

First, MOS only. P-MOS and CMOS using the same power supply of less than 15 V , Figure 3-4.

In this configuration CMOS drives P-MOS directly. However, P-MOS cannot drive CMOS directly because of its output will not pull down close enough to the lower power supply rail. $R_{\text {PD }}$ ( $R$ pull down) is added to each P-MOS output to pull it all the way down to the lower rail. Its value is selected such that it is small enough to give the desired RC time constant when pulling down but not so small that the P-MOS output cannot pull it virtually all the way up to the upper power supply rail when it needs to. This approach will work with push-pull as well as open drain P-MOS outputs.

Another approach in a purely MOS system is to build a cheap zener supply to bias up the lower power supply rail of CMOS, Figure 3-5.


FIGURE 3-5. A P-MOS and CMOS System Where The P-MOS Supply is Greater Than 15V.

In this configuration the P-MOS supply is selected to satisfy the P-MOS voltage requirement. The bias supply voltage is selected to reduce the total voltage across the CMOS (and therefore its logic swing) to match the minimum swing of the P-MOS
outputs. The CMOS can still drive P-MOS directly and now the P-MOS can drive CMOS with no pull-down resistors. The other restrictions are that the total voltage across the CMOS is less than 15 V and that the bias supply can handle the current requirements of all the CMOS. This approach is useful if the P-MOS supply must be greater than 15 V and the CMOS current requirement is low enough to be done easily with a small discrete component regulator.

If the system has bipolar logic, it will usually have at least two power supplies. In this case, the CMOS is run off the bipolar supply, and it interfaces directly to P-MOS, Figure 3-6.


Run the CMOS from the bipolar supply and interface directly to P-MOS
FIGURE 3-6. A System With CMOS, P-MOS and Bipolar Logic.

N-Channel MOS: interfacing to N-MOS is somewhat simpler than interfacing to P -MOS although similar problems exist. First, N-MOS requires lower power supplies than P-MOS, being in the range of 5 V to 12 V . This is directly compatible with CMOS. Second, N-MOS logic levels range from slightly above the lower power supply rail to about 1 to 2 V below the upper rail.

At the higher power supply voltages, N-MOS and CMOS can be interfaced directly since the N-MOS high logic level will be only about 10 to 20 percent below the upper rail. However, at lower supply voltages the N-MOS output level will be down 20 to 40 percent below the upper rail and something may have to be done to raise it. The simplest solu: tion is to add pull up resistors on the N-MOS outputs as shown in Figure 3-7.


Both operate off same supply with pull up resistors optional from N-MOS to CMOS.

FIGURE 3.7. A System With CMOS and N-MOS Only.

TTL, LPTTL, DTL: two questions arise when interfacing bipolar logic families to CMOS. First, is the bipolar family's logic " 1 " output voltage high enough to drive CMOS directly?

TTL，LPTTL，and DTL can drive 74C series CMOS directly over the commercial temperature range without external pull up resistors．However，TTL and LPTTL cannot drive 4000 series CMOS directly （DTL can）since 4000 series specs do not guarantee that a direct interface with no pull up resistors will operate properly．

DTL and LPTTL manufactured by National（NS LPTTL pulls up one diode drop higher than the LPTTL of other vendors）will also drive 74C directly over the entire military temperature range． LPTTL manufactured by other vendors and stan－ dard TTL will drive 74C directly over most of the mil temperature range．However，the TTL logic ＂ 1 ＂drops to a somewhat marginal level toward the lower end of the mil temperature range，and a pull up resistor is recommended．

According to the curve of DC margin vs $V_{\mathrm{Cc}}$ for CMOS in Figure 2－5，if the CMOS sees an input voltage greater than $\mathrm{V}_{\mathrm{CC}}-1.5 \mathrm{~V}\left(\mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}\right)$ ，the output is guaranteed to be less than 0.5 V from Ground．The next CMOS element will amplify this 0.5 V level to the proper logic levels of $\mathrm{V}_{\mathrm{Cc}}$ or Ground．The standard TTL logic＂ 1 ＂spec is a $V_{\text {OUT }}$ min ．of 2.4 V sourcing a current of $400 \mu \mathrm{~A}$ ．This is an extremely conservative spec since a TTL output will only approach a one level of 2.4 V under the extreme worst case conditions of lowest temperature，high input voltage（ 0.8 V ），highest possible leakage currents（into succeeding TTL devices），and $\mathrm{V}_{\mathrm{Cc}}$ at the lowest allowable（ $\mathrm{V}_{\mathrm{Cc}}=$ 4.5 V ）．

Under nominal conditions $\left(25^{\circ} \mathrm{C}, \mathrm{V}_{\text {IN }}=0.4 \mathrm{~V}\right.$ ， nominal leakage currents into CMOS and $\mathrm{V}_{\mathrm{Cc}}=$ 5 V ）a TTL logic＂ 1 ＂will be more like $\mathrm{V}_{\mathrm{Cc}}-2 \mathrm{~V}_{\mathrm{D}}$ ． or $\mathrm{V}_{\mathrm{cc}}-1.2 \mathrm{~V}$ ．Varying only temperature，the output will change by two times -2 mV per ${ }^{\circ} \mathrm{C}$ ，or -4 mV per ${ }^{\circ} \mathrm{C}$ ． $\mathrm{V}_{\mathrm{cc}}-1.2 \mathrm{~V}$ is more than enough to drive CMOS reliably without the use of a pull up resistor．

If the system is such that the TTL logic＂ 1 ＂output can drop below $\mathrm{V}_{\mathrm{cc}}-1.5 \mathrm{~V}$ ，use a pull up resistor to improve the logic＂ 1 ＂voltage into the CMOS．


Pull up resistor，RPu，is needed only at the lower end of the Mil temperature range．

FIGURE 3－8．TTL to CMOS Interface．

The second question is，can CMOS sink the bipolar input current and not exceed the maximum value of the bipolar logic zero input voltage？The logic ＂ 1 ＂input is no problem．

The LPTTL input current is small enough to allow CMOS to drive two loads directly．Normal power TTL input currents are ten times higher than those in LPTTL and consequently the CMOS out－ put voltage will be well above the input logic＂ 0 ＂ maximum of 0.8 V ．However，by carefully examin－ ing the CMOS output specs we will find that a two input NOR gate can drive one TTL load，albeit somewhat marginally．For example，the logical ＂ 0 ＂output voltage for both an MM74C00 and MM74C02 over temperature is specified at 0.4 V sinking $360 \mu \mathrm{~A}$（about $420 \mu \mathrm{~A}$ at $25^{\circ} \mathrm{C}$ ）with an input voltage of 4.0 V and a $\mathrm{V}_{\mathrm{cc}}$ of 4.75 V ．Both schematics are shown in Figure 3－9．


FIGURE 3－9a．MM74C00．


FIGURE 3－9b．MM74C02．

Both parts have the same current sinking spec but their structures are different．What this means is that either of the lower transistors in the MM74C02 can sink the same current as the two lower series transistors in the MM74C00．Both MM74C02 transistors together can sink twice the specified current for a given output voltage．If we allow the output voltage to go to 0.8 V ，then a MM 74 C 02 can sink four times $360 \mu \mathrm{~A}$ ，or 1.44 mA which is nearly 1.6 mA ．Actually， 1.6 mA is the maximum
spec for the TTL input current and most TTL parts run at about 1 mA . Also, $360 \mu \mathrm{~A}$ is the minimum CMOS sink current spec, the parts will really sink somewhere between 360 and $540 \mu \mathrm{~A}$ (between 2 and 3 LPTTL input loads). The $360 \mu \mathrm{~A}$ sink current is specified with an input voltage of 4.0 V . With an input voltage of 5.0 V , the sink current will be about $560 \mu \mathrm{~A}$ over temperature, making it even easier to drive TTL. At room temperature with an input voltage of 5 V , a CMOS output can sink about $800 \mu \mathrm{~A}$. A 2 input NOR gate, therefore, will sink about 1.6 mA with a $\mathrm{V}_{\text {OUT }}$ of about 0.4 V if both NOR gate inputs are at 5 V .

The main point of this discussion is that a common 2 input CMOS NOR gate such as an MM74C02
can be used to drive a normal TTL load in lieu of a special buffer. However, the designer must be willing to sacrifice some noise immunity over temperature to do so.

## TIMING CONSIDERATIONS IN CMOS MSIs

There is one more thing to be said in closing. All the flip-flops used in CMOS designs are genuinely edge sensitive. This means that the J-K flip-flops do not "ones catch" and that some of the timing restrictions that applied to the control lines on MSI functions in TTL have been relaxed in the 74C series.

## CMOS Linear Applications

PNP and NPN bipolar transistors have been used for many years in＂complementary＂type of amplifier circuits．Now，with the arrival of CMOS technology，complementary P－channel／ N －channel MOS transistors are available in monolithic form． The MM74C04 incorporates a P－channel MOS transistor and an N －channel MOS transistor connected in complementary fashion to function as an inverter．

Due to the symmetry of the P －and N －channel transistors，negative feedback around the comple－ mentary pair will cause the pair to self bias itself to approximately $1 / 2$ of the supply voltage． Figure 1 shows an idealized voltage transfer characteristic curve of the CMOS inverter con－ nected with negative feedback．Under these conditions the inverter is biased for operation about the midpoint in the linear segment on the steep transition of the voltage transfer character－ istic as shown in Figure 1.


FIGURE 1．Idealized Voltage Transfer Characteristics of an MM74C04 Inverter．

Under AC conditions，a positive going input will cause the output to swing negative and a negative going input will have an inverse effect．Figure 2 shows $1 / 6$ of a MM74CO4 inverter package connected as an AC amplifier．

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The power supply current is constant during dynamic operation since the inverter is biased for Class A operation．When the input signal swings near the supply，the output signal will become distorted because the P－N channel devices are driven into the non－linear regions of their transfer characteristics．If the input signal approaches the supply voltages，the P －or N －channel transistors become saturated and supply current is reduced to essentially zero and the device behaves like the classical digital inverter．


FIGURE 3．Voltage Transfer Characteristics for an Inverter Connected as a Linear Amplifier．

Figure 3 shows typical voltage characteristics of each inverter at several values of the $\mathrm{V}_{\mathrm{CC}}$ ．The shape of these transfer curves are relatively constant with temperature．Temperature affects for the self biased inverter with supply voltage is shown in Figure 4．When the amplifier is operating at 3 volts，the supply current changes drastically as a function of supply voltage because the MOS transistors are operating in the proximity of their gate－source threshold voltages．


FIGURE 4．Normalized Amplifier Supply Current Versus Ambient Temperature Characteristics．

Figure 5 shows typical curves of voltage gain as a function of operating frequency for various supply voltages．

Output voltages can swing within millivolts of the supplies with either a single or dual supply．


FIGURE 5．Typical Voltage Gain Versus Frequency Characteristics for Amplifier Shown in Figure 2.

## APPLICATIONS

## Cascading Amplifiers for Higher Gain．

By cascading the basic amplifier block shown in Figure 2 a high gain amplifier can be achieved．The gain will be multiplied by the number of stages used．If more than one inverter is used inside the feedback loop（as in Figure 6）a higher open loop gain is achieved which results in more accurate closed loop gains．


FIGURE 6．Three CMOS Inverters Used as an X10 AC Amplifier．

## Post Amplifier for Op Amps．

A standard operational amplifier used with a CMOS inverter for a Post Amplifier has several advantages．The operational amplifier essentially sees no load condition since the input impedance to the inverter is very high．Secondly，the CMOS inverters will swing to within millivolts of either supply．This gives the designer the advantage of operating the operational amplifier under no load conditions yet having the full supply swing capability on the output．Shown in Figure 7 is the LM4250 micropower Op Amp used with a 74C04 inverter for increased output capability while maintaining the low power advantage of both devices．


FIGURE 7．MM74C04 Inverter Used as a Post Amplifier for a Battery Operated Op Amp．

The MM74C04 can also be used with single supply amplifier such as the LM324．With the circuit shown in Figure 8，the open loop gain is approxi－ mately 160 dB ．The LM324 has 4 amplifiers in a package and the MM74C04 has 6 amplifiers per package．


FIGURE 8．Single Supply Amplifier Using a CMOS Cascade Post Amplifier with the LM324．

CMOS inverters can be paralleled for increased power to drive higher current loads．Loads of 5.0 mA per inverter can be expected under AC conditions．

Other 74C devices can be used to provide greater complementary current outputs．The MM 74 C 00 NAND Gate will provide approximately 10 mA
from the $\mathrm{V}_{\mathrm{CC}}$ supply while the MM74C02 will supply approximately 10 mA from the negative supply．Shown in Figure 9 is an operational amplifier using a CMOS power post amplifier to provide greater than 40 mA complementary currents．


FIGURE 9．MM74C00 and MM74C02 Used as a Post Amplifier to Provide Increased Current Drive．

## Other Applications．

Shown in Figure 10 is a variety of applications utilizing CMOS devices．Shown is a linear phase shift oscillator and an integrator which use the CMOS devices in the linear mode as well as＇a few circuit ideas for clocks and one shots．

## Conclusion

Careful study of CMOS characteristics show that CMOS devices used in a system design can be used for linear building blocks as well as digital blocks．

Utilization of these new devices will decrease package count and reduce supply requirements． The circuit designer now can do both digital and linear designs with the same type of device．


Phase Shift Oscillator Using MM74C04


Integrator Using Any Inverting CMOS Gate


Square Wave Oscillator


54C/74C Family Characteristics

## INTRODUCTION

The purpose of this 54C/74C Family Characteristics application note is to set down, in one place, all those characteristics which are common to the devices in the MM54C/MM74C logic family. The characteristics which can be considered to apply are:

1. Output voltage-current characteristics
2. Noise characteristics
3. Power consumption
4. Propagation delay (speed)
5. Temperature characteristics

With a good understanding of the above characteristics the designer will have the necessary tools to optimize his system. An attempt will be made to present the information in as simple a manner as possible to facilitate its use. This coupled with

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the fact that 54C/74C has the same function and pin-out as standard series $54 \mathrm{~L} / 74 \mathrm{~L}$ will make the application of CMOS to digital systems very straightforward.

## OUTPUT CHARACTERISTICS

Figure 1 and Figure 2 show typical output drain characteristics for the basic inverter used in the $54 \mathrm{C} / 74 \mathrm{C}$ family. For more detailed information on the operation of the basic inverter the reader is directed to application note AN-77, "CMOS, The Ideal Logic Family." Although more complex gates, and MSI devices, may be composed of combinations of parallel and series transistors the considerations that govern the output characteristics of the basic inverter apply to these more complex structures as well.

(A) Typical Output Sink Characteristic (N-Channel)

(B) Typical Output Source Characteristic (P-Channel)
figure 1

(A) Typical Output Sink Characteristic (N-Channel)

(B) Typical Output Source Characteristic (P-Channel)

FIGURE 2

The 54C/74C family is designed so that the output characteristics of all devices are matched as closely as possible. To ensure uniformity all devices are tested at four output conditions (see Figures 1 and 2). These points are:

| $\mathrm{V}_{\mathrm{cc}}=5.0 \mathrm{~V}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=5.0 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{DS}} \geq 1.75 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{DS}} \geq 5.0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & V_{I N}=0 \mathrm{~V} \\ & \left\|\left.\right\|_{\mathrm{DS}}\right\| \geq 1.75 \mathrm{~mA} \\ & \left\|\mathrm{~V}_{\mathrm{DS}}\right\| \geq 5.0 \mathrm{~V} \end{aligned}$ |
| :---: | :---: | :---: |
| $V_{c c}=10 \mathrm{~V}$ | $\mathrm{V}_{1 \mathrm{~N}}=10 \mathrm{~V}$ | $\mathrm{V}_{\text {IN }}=0 \mathrm{~V}$ |
|  | $\begin{aligned} & \mathrm{I}_{\mathrm{DS}} \geq 8.0 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{DS}} \geq 10 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \left\|\left.\right\|_{\mathrm{DS}}\right\| \geq 8.0 \mathrm{~mA} \\ & \left\|\mathrm{~V}_{\mathrm{DS}}\right\| \geq 10 \mathrm{~V} \end{aligned}$ |

Note that each device data sheet guarantees these points in the table of electrical characteristics.

The output characteristics can be used to determine the output voltage for any load condition. Figures 1 and 2 show load lines for resistive loads to $\mathrm{V}_{\mathrm{cc}}$ for sink currents and to GND for source currents. The intersections of this load line with the drain characteristic in question gives the output voltage. For example at $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=1.5 \mathrm{~V}$ (typ) with a load of $500 \Omega$ to ground.

These figures also show the guaranteed points for driving two 54L/74L standard loads. As can be seen there is typically ample margin at $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$.

In the case where the $54 \mathrm{C} / 74 \mathrm{C}$ device is driving another CMOS device the load line is coincident with the $I_{D S}=0$ axis and the output will then typically switch to either $V_{C C}$ or ground.

## NOISE CHARACTERISTICS

## Definition of Terms

Noise Immunity: The noise immunity of a logic element is that voltage which applied to the input will cause the output to change its output state.

Noise Margin: The noise margin of a logic element is the difference between the guaranteed logical " 1 " (" 0 ") level output voltage and the guaranteed logical " 1 " (" ${ }^{\prime \prime} 0^{\prime \prime}$ ) level input voltage.

The transfer characteristic of Figure 3 shows typical noise immunity and guaranteed noise margin for a $54 \mathrm{C} / 74 \mathrm{C}$ device operating at $\mathrm{V}_{\mathrm{CC}}=$ 10 V . The typical noise immunity does not change with voltage and is $45 \%$ of $V_{c c}$.


FIGURE 3. Typical Transfer Characteristic

All 54C/74C devices are guaranteed to have a noise margin of 1.0 V or greater over all operating conditions (see Figure 4).


FIGURE 4. Guaranteed Noise Margin Over Temperature vs $V_{C C}$

Noise immunity is an important device characteristic. However, noise margin is of more use to the designer because it very simply defines the amount of noise a system can tolerate under any circumstances and still maintain the integrity of logic levels.

Any noise specification to be complete must define how measurements are to be made. Figure 5 indicates two extreme cases; driving all inputs simultaneously and driving one input at a time. Both conditions must be included because each represents one worst case extreme.


FIGURE 5. Noise Margin Test Circuits

To guarantee a noise margin of 1.0 V , all $54 \mathrm{C} / 74 \mathrm{C}$ devices are tested under both conditions. It is important to note that this guarantees that every node within a system can have 1.0 V of noise, in logic " 1 " or logic " 0 " state, without malfunctioning. This could not be guaranteed without testing for both conditions in Figure 5.

## POWER CONSUMPTION

There are four sources of power consumption in CMOS devices: (1) leakage current (2) transient power due to load capacitance (3) transient power due to internal capacitance and (4) transient power due to current spiking during switching.

The first, leakage current, is the easiest to calculate and is simply the leakage current times $\mathrm{V}_{\mathrm{cc}}$. The data sheet for each specific device specifies this leakage current.

The second, transient power due to load capacitance, can be derived from the fact that the energy stored on a capacitor is $1 / 2 \mathrm{CV}^{2}$. Therefore every time the load capacitance is charged or discharged this amount of energy must be provided by the CMOS device. The energy per cycle is then $2\left[(1 / 2) C V_{c c}{ }^{2}\right]=C V_{c c}^{2}$. Energy per unit time, or power, is then $C V_{c c}{ }^{2} f$, where $C$ is the load capacitance and $f$ is the frequency.

The third, transient power due to internal capacitance takes exactly the same form as the load capacitance. Every device has some internal nodal capacitance which must be charged and discharged. This then represents another power term which must be considered.

The fourth, transient power due to switching current, is caused by the fact that whenever a CMOS device goes through a transition, with $V_{C c} \geq 2 V_{T}$, there is a time when both N -channel and P -channel devices are both conducting. An expression for this current is derived in application note AN-77. The expression is:
$P_{V I}=\frac{1}{2}\left(V_{C C}-2 V_{T}\right) I_{C C M A X}\left(t_{R I S E}+t_{F A L L}\right) f$
where:
$V_{T}=$ threshold voltage
$I_{\text {CC }}(\mathrm{MAX})=$ peak non-capacitive current during switching

## $f=$ frequency

Note that this expression, like the capacitive power term is directly proportional to frequency. If the $P_{\mathrm{VI}}$ term is combined with the term arising from the internal capacitance, a capacitance $\mathrm{C}_{\mathrm{PD}}$ may be defined which closely approximates the no load power consumption for a CMOS device when used in the following expression:

Power (no load) $=C_{P D} V_{C C}{ }^{2} f$
The total power consumption is then simplified to:

Total Power $=\left(C_{P D}+C_{L}\right) V_{C C}{ }^{2} f+I_{\text {LEAK }} V_{C C}(1)$

The procedure for obtaining $\mathrm{C}_{P D}$ is to measure the no load power at $V_{c c}=10 \mathrm{~V}$ vs frequency and calculate the value of $C_{\text {PD }}$ which corresponds to the measured power consumption. This value of $C_{P D}$ is given on each $54 C / 74 \mathrm{C}$ data sheet and with equation (1) the computation of power consumption is straightforward.

To simplify the task even further Figure 6 gives a graph of normalized power vs frequency for different power supply voltages. To obtain actual power consumption find the normalized power for a particular $\mathrm{V}_{\mathrm{CC}}$ and frequency, then multiply by $C_{P D}+C_{L}$.


FIGURE 6. Normalized Typical Power Consumption vs Frequency

As an example let's find the total power consumption for an MM74C00 operating at $f=100 \mathrm{kHz}$, $V_{C C}=10 \mathrm{~V}$ and $C_{L}=50 \mathrm{pF}$. From the curve, normalized power per gate equals $10 \mu \mathrm{~W} / \mathrm{pF}$. From the data sheet $\mathrm{C}_{\mathrm{PD}}=12 \mathrm{pF}$; therefore, actual power per gate is:

$$
\begin{aligned}
& \frac{\text { power }}{\text { gate }}=\frac{10 \mu \mathrm{~W}}{\mathrm{pF}} \times(12 \mathrm{pF}+50 \mathrm{pF})=\frac{0.62 \mathrm{~mW}}{\text { gate }} \\
& \text { total power }
\end{aligned} \begin{aligned}
\text { no. of gates } \\
\text { package }
\end{aligned} \frac{\text { power }}{\text { gate }}+I_{\text {LEAKAGE }} \times V_{\mathrm{CC}} \text {. }
$$

Up to this point the discussion of power consumption has been limited to simple gate functions. Power consumption for an MSI function is more complex but the same technique just derived applies. To demonstrate the technique let's compute the total power consumption of a MM74C161, four bit binary counter, at $V_{C c}=10 \mathrm{~V}, f=1 \mathrm{MHz}$ and $C_{L}=50 \mathrm{pF}$ on each output.

The no load power is still given by $\mathbf{P}$ (no load) $=$ $C_{P D} V_{C C}{ }^{2} f$. This demonstrates the usefulness of the concept of the internal capacitance, $\mathrm{C}_{\mathrm{PD}}$. Even through the circuit is very complex and has many nodes charging and discharging at various rates, all of the effects can be easily lumped into one easy to use term, $\mathrm{C}_{\mathrm{PD}}$.

Calculation of transient power due to load capaci－ tance is a little more complex since each output is switched at one half the rate of the previous output：Taking this into account the complete expression for power consumption is：


This reduces to：
$P_{\text {TOTAL }}=\left(C_{P D}+C_{L}\right) V_{C C}{ }^{2} f+I_{L} V_{C C}$

From the data sheet $C_{P D}=90 \mathrm{pF}$ and $\mathrm{I}_{\mathrm{L}}=0.05 \mu \mathrm{~A}$ ． Using Figure 6 total power is then：

$$
\begin{aligned}
P_{\text {TOTAL }}= & (90 \mathrm{pF}+50 \mathrm{pF}) \times \frac{100 \mu \mathrm{~W}}{\mathrm{pF}}+0.05 \times 10^{-6} \\
& \times 10 \mathrm{~V} \cong 14 \mathrm{~mW}
\end{aligned}
$$

This demonstrates that with more complex devices the concept of $\mathrm{C}_{\text {PD }}$ greatly simplifies the calcula－ tion of total power consumption．It becomes an easy task to compute power for different voltages and frequencies by use of Figure 6 and the equations above．

## PROPAGATION DELAY

Propagation delay for all 54C／74C devices is guaranteed with a load of 50 pF and input rise and fall times of 20 ns ．A 50 pF load was chosen， instead of 15 pF as in the 4000 series，because it is representative of loads commonly seen in CMOS systems．A good rule of thumb，in designing with CMOS，is to assume 10 pF of interwiring capaci－ tance．Operating at the specified propagation delay would allow 5 pF fanout for the 4000 series while $54 \mathrm{C} / 74 \mathrm{C}$ has a fanout of 40 pF ．A fanout of 5 pF （one gate input）is all but useless， and specified propagation delay would most prob－ ably not be realized in an actual system．

Operating at loads other than 50 pF poses a problem since propagation is a function of load capacitance．To simplify the problem Figure 7 has been generated and gives the slope of the propagation delay vs load capacitance line（ $\Delta \mathrm{t}_{\mathrm{pd}}$ ） pF ）as a function of power supply voltage．Because


FIGURE 7．Typical Propagation Delay per pF of Load Capacitance vs Power Supply
the propagation delay for zero load capacitance is not zero and depends on the internal structure of each device，an offset term must be added that is unique to a particular device type．Since each data sheet gives propagation delay for 50 pF the actual delay for different loads can be computed with the aid of the following equation：
$\left.t_{p d}\right|_{C_{L}=c}=(C-50) p F \times \frac{\Delta t_{p d}}{p F}+\left.t_{p d}\right|_{C_{L}=50 p F}$
where：
$C=$ Actual load capacitance
$\mathrm{t}_{\mathrm{pd}} \left\lvert\, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}=\begin{aligned} & \text { propagation delay with } 50 \mathrm{pF} \\ & \text { load，（specified on each de－} \\ & \text { vice data sheet）}\end{aligned}\right.$
$\frac{\Delta t_{\mathrm{pd}}}{\mathrm{pF}}=$ Value obtained from Figure 7.

As an example let＇s compute the propagation delay for an MM74C00 driving 15 pF load and operating with a $V_{c C}=5.0 \mathrm{~V}$ ．The equation gives：

$$
\begin{aligned}
\left.t_{p d}\right|_{C_{L}=15 \mathrm{pF}} & =(15-50) \mathrm{pF} \times 0.57 \frac{\mathrm{~ns}}{\mathrm{pF}}+50 \mathrm{~ns} \\
& =-20 \mathrm{~ns}+50 \mathrm{~ns}=30 \mathrm{~ns}
\end{aligned}
$$

The same formula and curves may be applied to more complex devices．For example the propaga－ tion delay from data to output for an MM 74 C 157 operating at $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ and $\mathrm{C}_{\mathrm{L}}=100 \mathrm{pF}$ is：
$\left.t_{\mathrm{pd}}\right|_{C_{L}=100 \mathrm{pF}}=(100-50) 0.29 \mathrm{~ns}+70 \mathrm{~ns}$

$$
=14.5+70 \cong 85 \mathrm{~ns}
$$

It is significant to note that this equation and Figure 7 apply to all 54C/74C devices. This is true because of the close match in drive characteristics of every device including MSI functions, i.e., the slope of the propagation delay vs load capacitance line at a given voltage is typically equal for all devices. The only exception is high fan-out buffers which have a smaller $\Delta \mathrm{t}_{\mathrm{pd}} / \mathrm{pF}$.
Another point to consider in the design of a CMOS system is the affect of power supply voltage on propagation delay. Figure 8 shows propagation delay as a function of $\mathrm{V}_{\mathrm{Cc}}$ and propagation delay times power consumption vs $\mathrm{V}_{\mathrm{cc}}$ for an MM74C00 operating with 50 pF load at $\mathrm{f}=100 \mathrm{kHz}$.


FIGURE 8. Speed Power Product and Propagation Delay vs $V_{\mathbf{C C}}$

Above $\mathrm{V}_{\mathrm{cc}}=5.0 \mathrm{~V}$ note the speed power product curve approaches a straight line. However the $t_{\text {pd }}$ curve starts to "flatten out." Going from

(A) Typical Output Drain Characteristic (N-Channel)

(A) Typical Output Drain Characteristic (N-Channel)
$V_{C C}=5.0 \mathrm{~V}$ to $V_{C C}=10 \mathrm{~V}$ gives a $40 \%$ decrease in propagation delay and going from $V_{c c}=10 \mathrm{~V}$ to $V_{C C}=15 \mathrm{~V}$ only decreases propagation delay by $25 \%$. Clearly for $\mathrm{V}_{\mathrm{cc}}>10 \mathrm{~V}$ a small increase in speed is gained by a disproportionate increase in power. Conversely, for small decreases in power below $\mathrm{V}_{\mathrm{cc}}=5.0 \mathrm{~V}$ large increases in propagation delay result.
Obviously it is optimum to use the lowest voltage consistent with system speed requirements. However in general it can be seen from Figure 8 that the best speed power performance will be obtained in the $\mathrm{V}_{\mathrm{cc}}=5.0 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{cc}}=10 \mathrm{~V}$ range.

## TEMPERATURE CHARACTERISTICS

Figures 9 and 10 give temperature variations in drain characteristics for the N -channel and P-channel devices operating at $V_{c c}=5.0 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{cc}}=10 \mathrm{~V}$ respectively. As can be seen from these curves the output sink and source current decreases as temperature increases. The affect is almost linear and can be closely approximated by a temperature coefficient of $-0.3 \%$ per degree centigrade.
Since the $t_{p d}$ can be entirely attributed to rise and fall time, the temperature dependance of $t_{p d}$ is a function of the rate at which the output load capacitance can be charged and discharged. This in turn is a function of the sink/source current which was shown above to vary as $-0.3 \%$ per degree centigrade. Consequently we can say that $t_{p d}$ varies as $-0.3 \%$ per degree centigrade. Actual measurements of $t_{p d}$ with temperature verifies this number.

(B) Typical Output Drain Characteristic (P-Channel)
FIGURE 9

(B) Typical Output Drain Characteristic (P-Channel)


FIGURE 11. Typical Gate Transfer Characteristics

The drain characteristics of Figure 9 and 10 show considerable variation with temperature. Examination of the transfer characteristics of Figure 11
indicates that they are almost independent of temperature. The transfer characteristic is not dependent on temperature because although both the N -channel and P -channel device characteristics change with temperature these changes track each other closely. The proof of this tracking is the temperature independance of the transfer characteristics. Noise margin and maximum/minimum logic levels will then not be dependent on temperature.

As discussed previously power consumption is a function of $\mathrm{C}_{\mathrm{PD}}, \mathrm{C}_{\mathrm{L}}, \mathrm{V}_{\mathrm{C}}, \mathrm{f}$ and $\mathrm{I}_{\text {Leakage }}$. All of these terms are essentially constant with temperature except $I_{\text {LEAKAGE. }}$. However, the leakage current specified on each 54C/74C device applies across the entire temperature range and therefore represents a worst case limit.

## CMOS Oscillators

## INTRODUCTION

This note describes several square wave oscillators that can be built using CMOS logic elements. These circuits offer the following advantages:

- Guaranteed startability
- Relatively good stability with respect to power supply variations
- Operation over a wide supply voltage range ( 3 V to 15 V )
- Operation over a wide frequency range from less than 1 Hz to about 15 MHz
- Low power consumption (see AN-90)
- Easy interface to other logic families and elements including TTL

Several RC oscillators and two crystal controlled oscillators are described. The stability of the RC oscillator will be sufficient for the bulk of applications; however, some applications will probably require the stability of a crystal. Some applications that require a lot of stability are:

1. Timekeeping over a long interval. A good deal of stability is required to duplicate the performance of an ordinary wrist watch (about 12 ppm ). This is, of course, obtainable with a crystal. However, if the time interval is short and/or the resolution of the timekeeping device is relatively large, an RC oscillator may be adequate. For example: if a stopwatch is built with a resolution of tenths of seconds and the longest interval of interest is two minutes, then an accuracy of 1 part in 1200 ( 2 minutes $\times 60$ seconds/minute $x$ 10 tenth/second) may be acceptable since any error is less than the resolution of the device.
2. When logic elements are operated near their specified limits. It may be necessary to maintain clock frequency accuracy within very tight limits in order to avoid exceeding the limits of the logic family being used, or in which the timing relationships of clock signals in dynamic MOS memory or shift register systems must be preserved.
3. Baud rate generators for communications equipment.

National Semiconductor Application Note 118 Mike Watts
4. Any system that must interface with other tightly specified systems. Particularly those that use a "handshake" technique in which Request or Acknowledge pulses must be of specific widths.

## LOGICAL OSCILLATORS

Before describing any specific circuits, a few words about logical oscillators may clear up some recurring confusion.

Any odd number of inverting logic gates will oscillate if they are tied together in a ring as shown in Figure 1. Many beginning logic designers have discovered this (to their chagrin) by inadvertently providing such a path in their designs. However, some people are confused by the circuit in Figure 1 because they are accustomed to seeing sinewave oscillators implemented with positive, feedback, or amplifiers with non-inverting gain. Since the concept of phase shift becomes a little strained when the inverters remain in their linear region for such a short period, it is far more straightforward to analyze the circuit from the standpoint of ideal switches with finite propagation delays rather than as amplifiers with $180^{\circ}$ phase shift. It then becomes obvious that a " 1 " chases itself around the ring and the network oscillates.


FIGURE 1. Odd Number of Inverters will Always Oscillate
The frequency of oscillation will be determined by the total propagation delay through the ring and is given by the following equation.

$$
f=\frac{1}{2 n T p}
$$

Where:

$$
\begin{aligned}
f & =\text { frequency of oscillation } \\
T p & =\text { Propagation delay per gate } \\
n & =\text { number of gates }
\end{aligned}
$$

This is not a practical oscillator, of course, but it does illustrate the maximum frequency at which such an oscillator will run. All that must be done to make this a useful oscillator is to slow it down to the desired frequency. Methods of doing this are described later.

To determine the frequency of oscillation, it is necessary to examine the propagation delay of the inverters. CMOS propagation delay depends on supply voltage and load capacitance. Several curves for propagation delay for National's 74C line of CMOS gates are reproduced in Figure 2. From these, the natural frequency of oscillation of an odd number of gates can be determined.

An example may be instructive.

Assume the supply voltage is 10 V . Since only one input is driven by each inverter, the load capacitance on each inverter is at most about 8 pF . Examine the curve in Figure $2 c$ that is drawn for $\mathrm{V}_{\mathrm{Cc}}=10 \mathrm{~V}$ and extrapolate it down to 8 pF . We see that the curve predicts a propagation delay of about 17 ns . We can then calculate the frequency of oscillation for three inverters using the expression mentioned above. Thus:

$$
f=\frac{1}{2 \times 3 \times 17 \times 10^{-9}}=9.8 \mathrm{MHz}
$$

Lab work indicates this is low and that something closer to 16 MHz can be expected. This reflects the conservative nature of the curves in Figure 2.

Since this frequency is directly controlled by propagation delays, it will vary a great deal with temperature, supply voltage, and any external loading, as indicated
by the graphs in Figure 2. In order to build a usefully stable oscillator it is necessary to add passive elements that determine oscillation frequency and minimize the effect of CMOS characteristics.

## STABLE RC OSCILLATOR

Figure 3 illustrates a useful oscillator made with three inverters. Actually, any inverting CMOS gate or combination of gates could be used. This means left over portions


FIGURE 3. Three Gate Oscilaltor
of gate packages can be often used. The duty cycle will be close to $50 \%$ and will oscillate at a frequency that is given by the following expression.

$$
f \cong \frac{1}{2 R 1 C\left(\frac{0.405 R 2}{R 1+R 2}+0.693\right)}
$$

Another form of this expression is:

$$
f \cong \frac{1}{2 C\left(0.405 R_{e q}+0.693 R 1\right)}
$$

Where:

$$
R_{\text {eq }}=\frac{R 1 R 2}{R 1+R 2}
$$



The following three special cases may be useful.
$\begin{array}{ll}\text { If } R 1=R 2=R & f \cong \frac{0.559}{R C} \\ \text { If } R 2 \ggg R 1 & f \cong \frac{0.455}{R C} \\ \text { If } R 2 \lll R 1 & f \cong \frac{0.722}{R C}\end{array}$
Figure 4 illustrates the approximate output waveform and the voltage $\mathrm{V}_{1}$ at the charging node.


FIGURE 4. Waveforms for Oscillator in Figure 3

Note that the voltage $V_{2}$ will be clamped by input diodes when $V_{1}$ is greater than $V_{c c}$ or more negative than ground. During this portion of the cycle current will flow through R2. At all other times the only current through R2 is a very minimal leakage term. Note also that as soon as $V_{1}$ passes through threshold (about $50 \%$ of supply) and the input to the last inverter begins to change, $\mathrm{V}_{1}$ will also change in a direction that reinforces the switching action; i.e., providing positive feedback. This further enhances the stability and predictability of the network.

This oscillator is fairly insensitive to power supply variations due largely to the threshold tracking close to $50 \%$ of the supply voltage. Just how stable it is will be determined by the frequency of oscillation; the lower the frequency the more stability and vice versa. This is because propagation delay and the effect of threshold shifts comprise a smaller portion of the overall period. Stability will also be enhanced if R1 is made large enough to swamp any variations in the CMOS output resistance.

## TWO GATE OSCILLATOR WILL NOT NECESSARILY OSCILLATE

A popular oscillator is shown in Figure 5a. The only undesirable feature of this oscillator is that it may not oscillate. This is readily demonstrated by letting the value of C go to zero. The network then degenerates into

Figure 5b, which obviously will not oscillate. This illustrates that there is some value of C 1 that will not force the network to oscillate. The real difference between this two gate oscillator and the three gate oscillator is that the former must be forced to oscillate by the capacitor while the three gate network will always oscillate willingly and is simply slowed, down by the capacitor. The three gate network will always oscillate, regardless of the value of C 1 but the two gate oscillator will not oscillate when C1 is small.

(a)

(b)

FIGURE 5. Less Than Perfect Oscillator

The only advantage the two gate oscillator has over the three gate oscillator is that it uses one less inverter. This may or may not be a real concern, depending on the gate count in each user's specific application. However, the next section offers a real minimum parts count oscillator.

## A SINGLE SCHMITT TRIGGER MAKES AN OSCILLATOR

Figure 6 illustrates an oscillator made from a single Schmitt trigger. Since the MM74C14 is a hex Schmitt trigger, this oscillator consumes only one sixth of a package. The remaining 5 gates can be used either as ordinary inverters like the MM74C04 or their Schmitt trigger characteristics can be used to advantage in the normal manner. Assuming these five inverters can be used elsewhere in the system, Figure 6 must represent the ultimate in low gate count oscillators.


FIGURE 6. Schmitt Trigger Oscillator

Voltage $\mathrm{V}_{1}$ is depicted in Figure 7 and changes between the two thresholds of the Schmitt trigger. If these thresholds were constant percentages of $\mathrm{V}_{\mathrm{Cc}}$ over the supply voltage range, the oscillator would be insensitive to variations in $\mathrm{V}_{\mathrm{Cc}}$. However, this is not the case. The thresholds of the Schmitt trigger vary enough to make the oscillator exhibit a good deal of sensitivity to $\mathrm{V}_{\mathrm{Cc}}$.

Applications that do not require extreme stability or that have access to well regulated supplies should not be bothered by this sensitivity to $\mathrm{V}_{\mathrm{cc}}$. Variations in threshold can be expected to run as high as four or five percent when $V_{c c}$ varies from 5 V to 15 V .


FIGURE 7. Waveforms for Schmitt Trigger Oscillator in Figure 6

## A CMOS Crystal Oscillator

Figure 8 illustrates a crystal oscillator that uses only one CMOS inverter as the active element. Any odd number of inverters may be used, but the total propagation delay through the ring limits the highest frequency
that can be obtained. Obviously, the fewer inverters that are used, the higher the maximum possible frequency.

## CONCLUSIONS

A large number of oscillator applications can be implemented with the extremely simple, reliable, inexpensive and versatile CMOS oscillators described in this note. These oscillators consume very little power compared to most other approaches. Each of the oscillators requires less than one full package of CMOS inverters of the MM74C04 variety. Frequently such an oscillator can be built using leftover gates of the MM74C00, MM74C02, MM74C10 variety. Stability superior to that easily attainable with TTL oscillators is readily attained, particularly at lower frequencies. These oscillators are so versatile, easy to build, and inexpensive that they should find their way into many diverse designs.


FIGURE 8. Crystal Oscillator

# Using the CMOS Dual Monostable Multivibrator 

## introduction

The MM54C221/MM74C221 is a dual CMOS monostable multivibrator. Each one-shot has three inputs ( $A, B$ and CLR) and two outputs ( Q and $\overline{\mathrm{Q}}$ ). The output pulse width is set by an external RC network.

The $A$ and $B$ inputs trigger an output pulse on a negative or positive input transition respectively. The CLR input when low resets the one-shot. Once triggered the $A$ and $B$ inputs have no further control on the output.

## THEORY OF OPERATION

Figure 1 shows that in its stable state, the one-shot clamps $\mathrm{C}_{\mathrm{EXT}}$ to ground by turning N 1 ON and holds the positive comparator input at $\mathrm{V}_{\mathrm{cc}}$ by turning N 2 OFF. The prefix N is used to denote N -channel transistors.

The signal, G, gating N2 OFF also gates the comparator OFF thereby keeping the internal power dissipation to an absolute minimum. The only power dissipation when in the stable state is that generated by the current through $R_{E X T}$. The bulk of this dissipation is in $R_{E X T}$ since the voltage drop across $N 1$ is very small for normal ranges of $R_{E X T}$.

To trigger the one-shot the CLR input must be high.

The gating, G , on the comparator is designed such that the comparator output is high when the one-shot is in its stable state. With the CLR input high the clear input to FF is disabled allowing the flip-flop to respond to the $A$ or $B$ input. $A$ negative transition on $A$ or a positive transition on $B$ sets $Q$ to a high state. This in turn gates N1 OFF, and N2 and the comparator ON.

Gating N2 ON establishes a reference of $0.63 \mathrm{~V}_{\mathrm{Cc}}$ on the comparator's positive input. Since the voltage on $\mathrm{C}_{\mathrm{EXT}}$ can not change instantaneously $\mathrm{V} 1=0 \mathrm{~V}$ at this time. The comparator then will maintain its one level on the output. Gating N1 OFF allows $\mathrm{C}_{E \times T}$ to start charging through $R_{E X T}$ toward $V_{C C}$ exponentially.

Assuming a perfect comparator (zero offset and infinite gain) when the voltage on $\mathrm{C}_{\mathrm{EXT}}, \mathrm{V} 1$, equals $0.63 \mathrm{~V}_{\mathrm{CC}}$ the comparator output will go from a high state to a low state resetting Q to a low state. Figure 2 is a timing diagram summarizing this sequence of events.

This diagram is idealized by assuming zero rise and fall times and zero propagation delay but it shows the basic operation of the one-shot. Also shown is the effect of taking the CLR input low. Whenever CLR goes low FF


FIGURE 1. Monostable Multivibrator Logic Diagram


FIGURE 2. One-Shot Timing Diagram
is reset independent of all other inputs. Figure 2 also shows that once triggered, the output is independent of any transitions on $B$ (or A) until the cycle is complete.

The output pulse width is determined by the following equation:

$$
\begin{equation*}
V_{1}=V_{C C}\left(1-e^{-T / R} E X T C_{E X T}\right)=0.63 V_{C C} \tag{1}
\end{equation*}
$$

Solving for t gives:

$$
\begin{equation*}
T=R_{E X T} C_{E X T} \ln (1 / 0.37)=R_{E X T} C_{E X T} \tag{2}
\end{equation*}
$$

A word of caution should be given in regards to the ground connection of the external capacitor ( $\mathrm{C}_{\mathrm{EXT}}$ ). It should always be connected as shown in Figure 1 to pin 14 or 6 and never to pin 8. This is important because of the parasitic resistor $R^{*}$. Because of the large discharge current through $R^{*}$, if the capacitor is connected to pin 8, a four layer diode action can result causing the circuit to latch and possibly damage itself.

## ACCURACY

There are many factors which influence the accuracy of the one-shot. The most important are:
a. Comparator input offset
b. Comparator gain
c. Comparator time delay
d. Voltage divider R1, R2
e. Delays in logic elements
f. ON impedance of N1 and N2
g. Leakage of N1
h. Leakage of $\mathrm{C}_{E X T}$
i. Magnitude of $R_{E X T}$ and $C_{E X T}$

The characteristics of $C_{E X T}$ and $R_{E X T}$ are, of course, not determined by the characteristics of the one-shot. In order to establish the accuracy of the one-shot, devices were tested using an external resistance of $10 \mathrm{k} \Omega$ and various capacitors. A resistance of $10 \mathrm{k} \Omega$ was chosen
because the leakage and ON impedance of transistor N1 have a minimal effect on accuracy with this value of resistance.

Two values of $\mathrm{C}_{\mathrm{EXT}}$ were chosen, 1000 pF and $0.1 \mu \mathrm{~F}$. These values give pulse widths of $10 \mu \mathrm{~s}$ and $1000 \mu \mathrm{~s}$ with $R_{E X T}=10 \mathrm{k} \Omega$.

Figures 3 and 4 show the resulting distributions of pulse widths at $25^{\circ} \mathrm{C}$ for various power supply voltages. Because propagation delays, at the same power supply voltage, are the same independent of pulse width, the shorter the pulse width the more the accuracy is


FIGURE 3. Typical Pulse Width Distribution for $10 \mu \mathrm{~s}$ Pulse.


FIGURE 4. Typical Pulse Width Distribution for $1000 \mu \mathrm{~s}$ Pulse.
affected by propagation delay. Figures 3 and 4 clearly show this effect. As pointed out in application note AN-90, 54C/74C Family Characteristics, propagation delay is a function of $\mathrm{V}_{\mathrm{cc}}$. Figure 3, (Pulse Width $=$ $10 \mu \mathrm{~s}$ ) shows much greater variation with $\mathrm{V}_{\mathrm{cc}}$ than Figure 4 (Pulse Width $=1000 \mu \mathrm{~s}$ ). This same information is shown in Figures 5 and 6 in a different format. In


FIGURE 5. Typical Percentage Deviation from $V_{C C}=10 \mathrm{~V}$ Value vs $V_{C C}(P W=10 \mu \mathrm{~s})$.


FIGURE 6. Typical Percentage Deviation from $V_{C C}=10 \mathrm{~V}$ Value vs $V_{C C}(P W=1000 \mu \mathrm{~s})$.
these figures the percent deviation from the average pulse width at $10 \mathrm{~V} \mathrm{~V}_{\mathrm{cc}}$ is shown vs $\mathrm{V}_{\mathrm{cc}}$. In addition to the average value the $10 \%$ and $90 \%$ points are shown. These percentage points refer to the statistical distribution of pulse width error. As an example, at $\mathrm{V}_{\mathrm{Cc}}=10 \mathrm{~V}$ for $10 \mu \mathrm{~s}$ pulse width, $90 \%$ of the devices have errors of less than $+1.7 \%$ and $10 \%$ have errors less than $-2.1 \%$. In other words, $80 \%$ have errors between $+1.7 \%$ and -2.1\%.

The minimum error can be obtained by operating at the maximum $V_{C C}$. A price must be paid for this and this price is, of course, increased power dissipation.


FIGURE 7. Typical Minimum Pulse Width and Power Dissipation vs VCC.

Figure 7 shows typical power dissipation vs $V_{C C}$ operating both sides of the one-shot at $50 \%$ duty cycle. Also shown in the same figure is typical minimum pulse width vs $\mathrm{V}_{\mathrm{cc}}$. The minimum pulse width is a strong function of internal propagation delays. It is obvious from these two curves that increasing $V_{c c}$ beyond 10 V will not appreciably improve inaccuracy due to propagation delay but will greatly increase power dissipation.

Accuracy is also a function of temperature. To determine the magnitude of its effects the one-shot was tested at temperature with the external resistance and capacitance maintained at $25^{\circ} \mathrm{C}$. The resulting variation is shown in Figures 8 and 9.


FIGURE 8. Typical Pulse Width Error vs Temperature ( $\mathrm{PW}=\mathbf{1 0} \boldsymbol{\mu} \mathrm{s}$ ).


FIGURE 9. Typical Pulse Width Error vs Temperature ( $\mathrm{PW}=\mathbf{1 0 0 0} \boldsymbol{\mu} \mathrm{s}$ ).

Up to this point the external timing resistor, $\mathrm{R}_{\mathrm{EXT}}$, has been held fixed at $10 \mathrm{k} \Omega$. In actual applications other values may be necessary to achieve the desired pulse width. The question then arises as to what effect this will have on accuracy.


As $R_{E X T}$ becomes larger and larger the leakage current on transistor N 1 becomes an ever increasing problem. The equivalent circuit for this leakage is shown in Figure 10.
$v(t)$ is given by:

$$
v(t)=\left(V_{C C}-I_{L} R_{E X T}\right)\left(1-e^{-t} / R_{E X T} C_{E X T}\right)
$$

As before, when $v(t)=0.63 \mathrm{~V}_{\mathrm{Cc}}$, the output will reset. Solving for $t_{L}$ gives:

$$
\begin{equation*}
t_{L}=R_{E X T} C_{E X T} \ln \left(\frac{V_{C C}-I_{L} R_{E X T}}{0.37 V_{C C}-I_{L} R_{E X T}}\right) \tag{3}
\end{equation*}
$$

Using $T$ as defined in Equation 2 the pulse width error is:

$$
\text { PW Error }=\frac{t_{L}-T}{T} \times 100 \%
$$

Substituting Equations 2 and 3 gives:

PW Error $=\frac{R_{E X T} C_{E X T} \ln \left(\frac{V_{C C}-I_{L} R_{E X T}}{0.37 V_{C C}-I_{L} R_{E X T}}\right)-R_{E X T} C_{E X T} \ln (1 / 0.37)}{R_{E X T} C_{E X T} \ln (1 / 0.37)}$

PW Error is plotted in Figure 11 for $\mathrm{V}_{\mathrm{Cc}}=5,10$ and 15 V . As expected, decreasing $\mathrm{V}_{\mathrm{cc}}$ causes PW Error to increase with fixed $I_{L}$. Note that the leakage current, although here assumed to flow through N1, is general and could also be interpreted as leakage through $\mathrm{C}_{\text {EXT }}$. See MM54C221/MM74C221 data sheet for leakage limits.


FIGURE 11. Percentage Pulse Width Error Due to Leakage.

To demonstrate the usefulness of Figure 11 an example will be most helpful. Let us assume that N 1 has a leakage of $250 \times 10^{-9} \mathrm{amps}, \mathrm{C}_{\mathrm{EXT}}$ has leakage of $150 \times 10^{-9} \mathrm{amps}$, output pulse width $=0.1$ seconds and $V_{C C}=5 \mathrm{~V}$. What $R_{E X T} C_{E X T}$ should be used to guarantee an error due to leakage of less than $5 \%$.

From Figure 11 we see that to meet these conditions $\mathrm{R}_{\mathrm{EXT}} \mathrm{I}_{\mathrm{L}}<0.14 \mathrm{~V}$.

Then:

$$
\begin{aligned}
\mathrm{R}_{\mathrm{EXT}} & <0.14 /(250+150) \times 10^{-9} \\
& <350 \mathrm{k} \Omega
\end{aligned}
$$

Choosing standard component values of $250 \mathrm{k} \Omega$ and $0.004 \mu \mathrm{~F}$ would satisfy the above conditions.

We have just defined the limitation on the maximum size of $R_{E X T}$. There is a corresponding limit on the minimum size that $R_{E X T}$ can assume. This is brought about because of the finite ON impedance of $N 1$. As $R_{E X T}$ is made smaller and smaller the amount of voltage across N1 becomes significant. The voltage across N1 is:

$$
\begin{equation*}
V_{N 1}=V_{C C} r_{O N} /\left(R_{E X T}+r_{O N}\right) \tag{4}
\end{equation*}
$$

The output pulse width is defined by:

$$
\begin{aligned}
v\left(t_{O}\right)= & \left(V_{C C}-V_{N 1}\right)\left(1-e^{-t_{O} / R_{E X T} C_{E X T}}\right) \\
& +V_{N 1}=0.63 V_{C C}
\end{aligned}
$$

Solving for $t_{\mathrm{O}}$ gives:

$$
\mathrm{t}_{\mathrm{O}}=R_{E X T} C_{E X T} \ln \left(\frac{\mathrm{~V}_{\mathrm{CC}}-\mathrm{V}_{\mathrm{N} 1}}{0.37 \mathrm{~V}_{\mathrm{CC}}}\right)
$$

Pulse Width Error is then:

$$
\text { PW Error }=\frac{t_{0}-T}{T} \times 100 \%
$$

Substituting Equations 2 and 4 gives:

$$
=\frac{R_{E X T} C_{E X T} \ln \left(\frac{V_{C C}-V_{N 1}}{0.37 V_{C C}}\right)-R_{E X T} C_{E X T} \ln (1 / 0.37)}{R_{E X T} C_{E X T} \ln (1 / 0.37)}
$$

This function is plotted in Figure 12 for $r_{\mathrm{ON}}$ of $50 \Omega$, $25 \Omega$ and $16.7 \Omega$. These are the typical values of $r_{O N}$ for a $\mathrm{V}_{\mathrm{cc}}$ of $5 \mathrm{~V}, 10 \mathrm{~V}$ and 15 V respectively.

As an example, assume that the pulse width error due to $r_{\text {ON }}$ must be less than $0.5 \%$ operating at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$. The typical value of $r_{O N}$ for $V_{C C}=5 \mathrm{~V}$ is $50 \Omega$. Referring to


FIGURE 12. Percentage Pulse Width Error Due to Finite roN of Transistor N1 vs REXT.
the $50 \Omega$ curve in Figure $12, \mathrm{R}_{\mathrm{EXT}}$ must be greater than $10 \mathrm{k} \Omega$ to maintain this accuracy. At $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{R}_{\mathrm{EXT}}$ must be greater than $5 \mathrm{k} \Omega$ as can be seen from the $25 \Omega$ curve in Figure 12.

Although clearly shown on the MM54C221/MM74C221 data sheet, it is worthwhile, for the sake of clarity, to point out that the parasitic capacitance between pins 7 (15) and 6 (14) is typically 15 pF. This capacitor is in parallel with $C_{E X T}$ and must be taken into account when accuracy is critical.


Frequency Magnitude Comparator

TYPICAL APPLICATIONS (Continued)


Analog Multiplier/Divider

CMOS Schmitt Trigger
-a Uniquely Versatile
Design Component

## INTRODUCTION

The Schmitt trigger has found many applications in numerous circuits, both analog and digital. The versatility of a TTL Schmitt is hampered by its narrow supply range, limited interface capability, low input impedance and unbalanced output characteristics. The Schmitt trigger could be built from discrete devices to satisfy a particular parameter, but this is a careful and sometimes time-consuming design.

The CMOS Schmitt trigger, which comes six to a package, uses CMOS characteristics to optimize design and advance into areas where TTL could not go. These areas include: interfacing with op amps and transmission lines, which operate from large split supplies, logic level conversion, linear operation, and special designs relying on a CMOS characteristic. The CMOS Schmitt trigger has the following advantages:

- High impedance input ( $10^{12} \Omega$ typical)
- Balanced input and output characteristics
- Thresholds are typically symmetrical to $1 / 2 \mathrm{~V}_{\mathrm{Cc}}$
- Outputs source and sink equal currents
- Outputs drive to supply rails
- Positive and negative-going thresholds show low variation with respect to temperature
- Wide supply range ( $3-15 \mathrm{~V}$ ), split supplies possible
- Low power consumption, even during transitions
- High noise immunity, $0.70 \mathrm{~V}_{\mathrm{cc}}$ typical

Applications demonstrating how each of these characteristics can become a design advantage will be given later in the application note.

## ANALYZING THE CMOS SCHMITT

The input of the Schmitt trigger goes through a standard input protection and is tied to the gates of four stacked devices. The upper two are P-channel and the lower two are N-channel. Transistors P3 and N3 are operating in the source follower mode and introduce hysteresis by feeding back the output voltage, out', to two different points in the stack.

When the input is at 0 V , transistors P 1 and P 2 are ON , and N1, N2 and P3 are OFF. Since out' is high, N3 is ON and acting as a source follower, the drain of N 1 , which is the source of $N 2$, is at $V_{C C}-V_{T H}$. If the input voltage is ramped up to one threshold above ground transistor N1 begins to turn ON, N1 and N3 both being ON form a voltage divider network biasing the source of N2 at roughly half the supply. When the input is a threshold above $1 / 2 \mathrm{~V}_{\mathrm{CC}}, \mathrm{N} 2$ begins to turn ON and regenerative switching is about to take over. Any more voltage on the input causes out' to drop. When out' drops, the source of N3 follows its gate, which is out', the influence of N3 in the voltage divider with N1 rapidly diminishes, bringing out' down further yet. Meanwhile P3 has started to turn ON, its gate being brought low by the rapidly dropping out'. P3 turning ON brings the source of P2 low and turns P2 OFF. With P2 OFF, out' crashes down. The snapping action is due to greater than unity loop gain through the stack caused by positive feedback through the source follower transistors. When the input is brought low again an identical process occurs in the upper portion of the stack and the snapping action takes place when the lower threshold is reached.


FIGURE 1. CMOS Schmitt Trigger

Out' is fed into the inverter formed by P4 and N4; another inverter built with very small devices, P5 and N5, forms a latch which stabilizes out'. The output is an inverting buffer capable of sinking $360 \mu \mathrm{~A}$ or two LPTTL loads.

The typical transfer characteristics are shown in Figure 2; the guaranteed trip point range is shown in Figure 3.

## WHAT HYSTERESIS CAN DO FOR YOUR

Hysteresis is the difference in response due to the direction of input change. A noisy signal that traverses the threshold of a comparator can cause multiple transitions at the output, if the response time of the comparator is less than the time between spurious effects. A Schmitt trigger has two thresholds: any spurious effects must be greater than the threshold difference to cause multiple transitions. With a CMOS Schmitt at $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ there is
typically 3.6 V of threshold difference, enough hysteresis to overcome almost any spurious signal on the input.

A comparator is often used to recover information sent down an unbalanced transmission line. The threshold of the comparator is placed at one half the signal amplitude (See Figure 4b). This is doen to prevent slicing level distortion. If a $4 \mu$ s wide signal is sent down a transmission line a $4 \mu \mathrm{~s}$ wide signal should be received or signal distortion occurs. If the comparator has a threshold above half the signal amplitude, then positive pulses sent are shorter and negative pulses are lengthened (See Figure 4c). This is called slicing level distortion. The Schmitt trigger does have a positive offset, $\mathrm{V}_{\mathrm{T}+}$, but it also has a negative offset $\mathrm{V}_{\mathrm{T}-}$. In CMOS these offsets are approximately symmetrical to half the signal level so a $4 \mu$ s wide pulse sent is also recovered (see Figure $4 d$ ). The recovered pulse is delayed in time but the length is not changed, so noise immunity is achieved and signal distortion is not introduced because of threshold offsets.


FIGURE 2. Typical CMOS Transfer Characteristics for Three Different Supply Voltages.


FIGURE 3. Guaranteed Trip Point Range.


FIGURE 4. CMOS Schmitt Trigger Ignores Noise

b) By using split supply $( \pm 1.5$ to $\pm 7.5)$ direct interface is achueved.

FIGURE 5. Sine to Square Wave Converter with Symmetrical Level Detection.


FIGURE 6. Diode Dump Tach Accepts any Input Waveform.

## APPLICATIONS OF THE CMOS SCHMITT

Most of the following applications use a CMOS Schmitt characteristic to either simplify design or increase performance. Some of the applications could not be done at all with another logic family.

The circuit in Figure 5a is the familiar sine to square wave converter. Because of input symmetry the Schmitt trigger is easily biased to achieve a $50 \%$ duty cycle. The high input impedance simplifies the selection of the biasing resistors and coupling capacitor. Since CMOS has a wide supply range the Schmitt trigger could be powered from split supplies (see Figure 5b). This biases the mean threshold value around zero and makes direct coupling from an op amp output possible.

In Figure 4, we see a frequency to voltage converter that accepts many waveforms with no change in output voltage. Although the energy in the waveforms are quite different, it is only the frequency that determines the output voltage. Since the output of the CMOS Schmitt pulls completely to the supply rails, a constant voltage swing across capacitor C1 causes a current to flow through the capacitor, dependent only on frequency. On positive output swings, the current is dumped to ground through D1. On negative output swings, current is pulled from the inverting op amp node through D2 and transformed into an average voltage by R2 and C2.

Since the CMOS Schmitt pulls completely to the supply rails the voltage change across the capacitor is just the supply voltage.

Schmitt triggers are often used to generate fast transitions when a slowly varying function exceeds a predetermined level. In Figure 7, we see a typical circuit, a light activated switch. The high impedance input of the CMOS Schmitt trigger makes biasing very easy. Most photo cells are several $\mathrm{k} \Omega$ brightly illuminated and a couple $M \Omega$ dark. Since CMOS has a $10^{12} \Omega$ typical input impedance, no effects are felt on the input when the output changes. The selection of the biasing resistor is just the solution of a voltage divider equation.

A CMOS application note wouldn't be complete without a low power application. Figure 8 shows a simple RC oscillator. With only six R's and C's and one Hex CMOS
trigger, six low power oscillators can be built. The square wave output is approximately $50 \%$ duty cycle because of the balanced input and output characteristics of CMOS. The output frequency equation assumes that $t_{1}=t_{2} \gg$ $t_{p d 0}+t_{p d 1}$.

We earlier saw how the CMOS Schmitt increased noise immunity on an unbalanced transmission line. Figure 9 shows an application for a balanced or differential transmission line. The circuit in Figure $7 a$ is CMOS EXCLUSIVE OR, the MM74C86, which could also be built from inverters, and NAND gates. If unbalanced information is generated on the line by signal crosstalk or external noise sources, it is recognized as an error.


FIGURE 7. Light Activated Switch couldn't be Simpler. The Input Voltage Rises as Light Intensity Increases, when $V_{T+}$ is Reached, the Output will go Low and Remain Low until the Intensity is Reduced Significantly.
 Input and Output Characteristics give the Output Frequency a Typically 50\% Duty Cycle.


FIGURE 9. Increase Noise Immunity by using the CMOS Schmitt Trigger to Demodulate a Balanced Transmission Line.

The circuit in Figure $9 b$ is a differential line receiver that recovers balanced transmitted data but ignores unbalanced signals by latching up. If both circuits of Figure 9 were used together, the error detector could signal the transmitter to stop transmission and the line receiver would remember the last valid information bit when unbalanced signals persisted on the line. When balanced signals are restored, the receiver can pick up where it left off.

The standard voltage range for CMOS inputs is $\mathrm{V}_{\mathrm{CC}}$ +0.3 V and ground -0.3 V . This is because the input protection network is diode clamped to the supply rails. Any input exceeding the supply rails either sources or sinks a large amount of current through these diodes. Many times an input voltage range exceeding this is desirable; for example, transmission lines often operate from $\pm 12 \mathrm{~V}$ and op amps from $\pm 15 \mathrm{~V}$. A solution to this problem is found in the MM74C914. This new device has an uncommon input protection that allows the input signal to go to 25 V above ground, and 25 V below $\mathrm{V}_{\mathrm{cc}}$. This means that the Schmitt trigger in the sine to square wave converter, in Figure 5b, could be powered by $\pm 1.5 \mathrm{~V}$ supplies and still be directly compatible with an op amp powered by $\pm 15 \mathrm{~V}$ supplies.

A standard input protection circuit and the new input protection are shown in Figure 10. The diodes shown have a 35 V breakdown. The input voltage can go positive until reverse biased D2 breaks down through forward bias D3, which is 35 V above ground. The input voltage can go negative until reverse biased D1 breaks down through forward bias D 2 , which is 35 V below $\mathrm{V}_{\mathrm{CC}}$. Adequate input protection against static charge is still maintained.

CMOS can be linear over a wide voltage range if proper consideration is paid to the biasing of the inputs. Figure 11 shows a simple VCO made with a CMOS inverter, acting as an integrator, and a CMOS Schmitt, acting as a comparator with hysteresis. The inverter integrates the positive difference between its threshold and the input voltage $\mathrm{V}_{I N}$. The inverter output ramps up until the positive threshold of the Schmitt trigger is reached. At that time, the Schmitt trigger output goes low, turning on the transistor through $\mathrm{R}_{\mathrm{s}}$ and speeding up capacitor $\mathrm{C}_{\mathrm{s}}$. Hysteresis keeps the output low until the integrating capacitor $C$ is discharged through $R_{D}$. Resistor $R_{D}$ should be kept much smaller than RC to keep reset time negligible. The output frequency is given by

$$
f_{\mathrm{O}}=\frac{V_{\mathrm{TH}}-V_{I N}}{\left(\mathrm{~V}_{\mathrm{T}+}-V_{\mathrm{T}-}\right)} \mathrm{R}_{\mathrm{CC}} .
$$

The frequency dependence with control voltage is given by the derivative with respect to $V_{I N}$ So,

$$
\frac{d f_{O}}{d V_{I N}}=\frac{-1}{\left(V_{T_{+}}-V_{T_{-}}\right) R C}
$$

where the minus sign indicates that the output frequency increases as the input is brought further below the inverter threshold. The maximum output frequency occurs when $V_{\text {IN }}$ is at ground and the frequency will decrease as $V_{\text {IN }}$ is raised up and will finally stop oscillating at the inverter threshold, approximately $0.55 \mathrm{~V}_{\mathrm{cc}}$.


FIGURE 10. Input Protection Diodes, in a) Normally Limit the Input Voltage Swing to 0.3 V above $V_{C C}$ and 0.3 V below Ground. In b) D2 or D1 is Reverse Biased Allowing Input Swings of 25 V above Ground or 25 V below $\mathrm{V}_{\mathrm{CC}}$.


$$
f_{O}=\frac{V_{T H}-V_{I N}}{\left(V_{T+}-V_{T}\right) \dot{R}_{C} C}
$$

$$
\frac{d f_{0}}{d V_{I N}}=\frac{-1}{\left(V_{T+}-V_{T}\right) R_{C} C}
$$

FIGURE 11. Linear CMOS (Voltage Controlled Oscillator)

The pulses from the VCO output are quite narrow because the reset time is much smaller than the integration time. Pulse stretching comes quite naturally to a Schmitt trigger. A one-shot or pulse stretcher made with an inverter and Schmitt trigger is shown in Figure 12. A positive pulse coming into the inverter causes its output to go low, discharging the capacitor through the diode D1. The capacitor is rapidly discharged, so the Schmitt input is brought low and the output goes positive. Check the size of the capacitor to make sure that inverter can fully discharge the capacitor in the input pulse time, or

$$
I_{\text {SINK INVERTER }}>\frac{C \Delta V}{\Delta T}+\frac{\Delta V}{R}
$$

where $\Delta V=V_{\text {cc }}$ for CMOS, and $\Delta T$ is the input pulse width.

For very narrow pulses, under 100 ns , the capacitor can be omitted and a large resistor will charge up the CMOS gate capacitance just like a capacitor.

When the inverter input returns to zero, the blocking diode prevents the inverter from charging the capacitor and the resistor must charge it from its supply. When the input voltage of the Schmitt reaches $\mathrm{V}_{\mathrm{T}+}$, the Schmitt output will go low sometime after the input pulse has gone low.

## THE SCHMITT SOLUTION

The Schmitt trigger, built from discrete parts, is a careful and sometimes time-consuming design. When introduced in integrated TTL, a few years ago, many circuit designers had renewed interest because it was a building block part. The input characteristics of TTL often make biasing of the trigger input difficult. The outputs don't source as much as they sink, so multivibrators don't have $50 \%$ duty cycle, and a limited supply range hampers interfacing with non 5 V parts.

The CMOS Schmitt has a very high input impedance with thresholds approximately symmetrical to one half the supply. A high voltage input is available. The outputs sink and source equal currents and pull directly to the supply rails.

A wide threshold range, wide supply range, high noise immunity, low power consumption, and low board space make the CMOS Schmitt a uniquely versatile part.

Use the Schmitt trigger for signal conditioning, restoration of levels, discriminating noisy signals, level detecting with hysteresis, level conversion between logic families, and many other useful functions.

The CMOS Schmitt is one step closer to making design limited only by the imagination of the designer.


FIGURE 12. Pulse Stretcher. A CMOS Inverter Discharges a Capacitor, a Blocking Diode allows Charging through R only. Schmitt Trigger Output goes Low after the RC Delay.

## Designing with MM74C908, MM74C918 Dual High Voltage CMOS Drivers

## INTRODUCTION

By combining the merits of both CMOS and bipolar technologies on a single silicon chip, the MM74C908, MM74C918 provides the following distinguished features as general purpose high voltage drivers.

- Wide supply voltage range ( 3 V to 18 V )
- High noise immunity (typ 0.45 V CC )
- High input impedance (typ $10^{12} \Omega$ )
- Extremely low standby power consumption (typ 750 nW at 15 V )
- Low output "ON" resistance (typ $8 \Omega$ )
- High output drive capability (IOUT $\geq 250 \mathrm{~mA}$ at $\mathrm{V}_{\text {OUT }}=\mathrm{V}_{\mathrm{CC}}-3 \mathrm{~V}$, and $\left.\mathrm{T}_{\mathrm{j}}=65^{\circ} \mathrm{C}\right)$
- High output "OFF" voltage

Among these, the first 4 are typical and unique characteristics of CMOS technology which are fully utilized in this circuit to achieve all the design advantages in a typical CMOS system.

The high output currents and low "ON" resistance are achieved through the use of an NPN Darlington pair at the output stage.

The MM74C908 is housed in an 8-lead epoxy dual-in-line package, which can dissipate at least 1.14 W . The higher power version, MM74C918, comes in a 14-lead epoxy dual-in-line package, with power capability up to a minimum of 2.27 W .

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The circuitry for each of the 2 identical sections is shown in Figure 1.

With both inputs sitting at logical " 1 " level, the output of the inverter is also at logical " 1 ", which prevents the P -channel transistor from being turned "ON"; therefore, the output is in its "OFF" state. Only a small amount of leakage current can flow.

On the other hand, when one or both of the inputs is at logical " 0 " level, the output of the inverter is also at logical " 0 ", which turns on the P-channel transistor and, hence, the Darlington pair.

## POWER CONSIDERATION

To assure junction temperature of $150^{\circ} \mathrm{C}$ or less, the on-chip power consumption must be limited to within the power handling capability of the packages. In Figure 2, the maximum power dissipation on-chip is shown as a function of ambient temperature for both MM74C908 and MM74C918. These curves are generated from (1) at $T_{j}=T_{j}(M A X)=150^{\circ} \mathrm{C}$.

$$
\begin{equation*}
\mathrm{T}_{\mathrm{j}}=\mathrm{T}_{\mathrm{A}}+\mathrm{P}_{\mathrm{D}} \theta_{\mathrm{j}} \mathrm{~A} \tag{1}
\end{equation*}
$$

where $T_{j}=$ junction temperature
$T_{A}=$ ambient temperature
$\mathrm{P}_{\mathrm{D}}=$ power dissipation
$\theta_{\mathrm{jA}}=$ thermal resistance between junction and ambient


FIGURE 1


FIGURE 2. Maximum Power Dissipation vs Ambient Temperature


FIGURE 3

For both sections $A$ and $B$ ；

$$
\begin{equation*}
\text { IOUT }=\frac{V_{C C}-\dot{V}_{L}}{R_{O N}+R_{L}} \tag{2}
\end{equation*}
$$

The device＂ON＂resistance， $\mathrm{R}_{\mathrm{ON}}$ ，is a function of junction temperature， $\mathrm{T}_{\mathrm{j}}$ ．The worst－case $\mathrm{R}_{\mathrm{ON}}$ as a function of $T_{j}$ is given in（3）．

$$
\begin{equation*}
\mathrm{R}_{\mathrm{ON}}=9\left[1+0.008\left(\mathrm{~T}_{\mathrm{j}}-25\right)\right] \tag{3}
\end{equation*}
$$

The total power dissipation in the device also consists of normal CMOS power terms（due to leakage current， internal capacitance，switching etc．）which are insignifi－ cant compared to the power dissipated at the output stages．Thus，the output power term defines the allowable limits of operation and is given by：

$$
\begin{align*}
P_{D} & =P_{D A}+P_{D B}  \tag{4}\\
& =1^{2} \text { OUTA } \cdot R_{O N}+1^{2} \text { OUTB } \cdot R_{O N}
\end{align*}
$$

Given R LA and $R_{\text {LB }}$ ，（1），（2），（3），（4）can be used to calculate $P_{D}, T_{j}$ ，etc．through iteration．

For example，let $V_{L}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=10 \mathrm{~V}, R_{\mathrm{LA}}=100 \Omega$ ， $R_{\mathrm{LB}}=50 \Omega, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \theta_{\mathrm{jA}}=110^{\circ} \mathrm{C} / \mathrm{W}$ ．

Assume：
$\mathrm{R}_{\mathrm{ON}}=12.28 \Omega$
By（2）：

$$
\begin{aligned}
& \text { IOUTA }=\frac{10}{12.28+100}=0.089 \mathrm{~A} \\
& \text { IOUTB }=\frac{10}{12.28+50}=0.161 \mathrm{~A}
\end{aligned}
$$

By（4）：

$$
P_{D}=(0.089)^{2} \cdot 12.28+(0.161)^{2} \cdot 12.28=0.41 \mathrm{~W}
$$

By（1）：

$$
T_{j}=70.5^{\circ} \mathrm{C}
$$

And by（3）：

$$
\mathrm{R}_{\mathrm{ON}}=12.28 \Omega
$$

## DESIGN TECHNIQUE

In a typical design，$R_{L}$ must be chosen to satisfy the load requirement（e．g．，a minimum current to turn on a relay）and at the same time，the power consumed in the driver package must be kept below its maximum power handling capability．

To minimize the design effort，a graphical technique is developed，which combines all the parameters in one plot，which can be used efficiently to obtain an optimal design．

Assume $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ and that both sections of the MM74C908 in Figure 3 are operating under identical conditions．The maximum allowable package dissipation is：

$$
\begin{align*}
P_{D} & =2\left(V_{C C}-V_{\text {OUT }}\right) \times \text { IOUT }  \tag{6}\\
& =\frac{1}{110}\left(150-T_{A}\right)=1.14 W
\end{align*}
$$

where $T_{j}=150^{\circ} \mathrm{C}, \theta_{j A}=110^{\circ} \mathrm{C} / \mathrm{W}$ are used in（1）per the data sheet．

Thus，the maximum power allowed in each section is：

$$
P_{D}=\left(V_{C C}-V_{O U T}\right) \times I_{O U T}=0.57 W
$$

A constant power curve $\mathrm{P}_{\mathrm{D}}=0.57 \mathrm{~W}$ can then be plotted as shown in Figure 4．The circuit must operate below this curve．Any voltage－current combination beyond it （in the shaded region）will not guarantee $T_{j}$ to be lower than $150^{\circ} \mathrm{C}$ ．

For any given $R_{L}$ ，a load line（7）can be superimposed on Figure 4.

IOUT $=\frac{1}{R_{L}}\left(V_{C C}-V_{L}\right)-\frac{1}{R_{L}}\left(V_{C C}-V_{\text {OUT }}\right)$

The slope of this load line is $-1 / R_{L}$ and it intersects with the vertical and horizontal axes at $1 / R_{\mathrm{L}}\left(\mathrm{V}_{\mathrm{CC}}-\right.$ $V_{L}$ ）and $V_{C C}-V_{L}$ respectively．

Given $\mathrm{V}_{\mathrm{CC}}$ and $\mathrm{V}_{\mathrm{L}}$ ，a minimum $\mathrm{R}_{\mathrm{L}}$ can be obtained by drawing the load line tangent to the constant power curve．In Figure 4，at $\mathrm{V}_{\mathrm{C}}-\mathrm{V}_{\mathrm{L}}=5 \mathrm{~V}$ the line inter－ sects IOUT axis at IOUT $=450 \mathrm{~mA}$ ．Thus， R $\mathrm{L}(\mathrm{MIN})=$ $5 \mathrm{~V} / 450 \mathrm{~mA}=11.1 \Omega$ ．Any $\mathrm{R}_{\mathrm{L}}$ value below this will move the intersecting point up and cause a section of the load line to extend into the shaded region．Therefore， the junction temperature can exceed $\mathrm{T}_{\mathrm{j}}(\mathrm{MAX})=150^{\circ} \mathrm{C}$ in the worst case if the circuit operates on such a section of the load line．

Whether this situation will occur or not is determined by both the value of $\mathrm{V}_{\mathrm{C}}-\mathrm{V}_{\mathrm{L}}$ and the $\mathrm{R}_{\mathrm{ON}}$ range of the drivers．


By (3), at $T_{j}=150^{\circ} \mathrm{C}$ RON(MAX) $=18 \Omega$, this is a straight line* passing through the origin with a slope of IOUT/(V $\left.V_{C C}-V_{\text {OUT }}\right)=1 / 18$ mho and intersects the load line at point $A$. Similarly, point $B$ and $C$ can be found for typical $(\sim 10 \Omega 2)$ and minimum $(\sim 5 \Omega)$ RON at $\mathrm{T}_{\mathrm{j}}=150^{\circ} \mathrm{C}$.

For $V_{C C}-V_{L}=5 V$, the tangent point falls between $A$ and $C$. Hence, $R_{L} \geq 11.1 \Omega$ calculated above must be satisfied; otherwise, part of the load line within the specified RON range will extend into the shaded region and therefore, $\mathrm{T}_{\mathrm{j}} \geq 150^{\circ} \mathrm{C}$ may occur.

For $V_{C C}-V_{L}=10 \mathrm{~V}$, however, a section of the load line can go beyond the $\mathrm{PD}_{\mathrm{D}}=0.57 \mathrm{~W}$ curve without affecting the safe operation of the circuit. By inspection of Figure 4, the reason is clear-the load line extends into the shaded region only outside of the specified $R_{\text {ON }}$ range (to the right of point $A^{\prime}$ ). Within the RON range, the load line lies below the $P_{D}=0.57 \mathrm{~W}$ curve, thus, a safe operation.

To a first approximation ${ }^{* *}$, the section of the load line between $A$ and $C$ is the operating range for the circuit at $V_{C C}-V_{L}=5 \mathrm{~V}$ and $R_{L}=11.1 \Omega$. Hence, the available current and voltage ranges for this circuit are $310 \mathrm{~mA} \geq$ IOUT $\geq 172 \mathrm{~mA}$ and $3.4 \mathrm{~V} \geq \mathrm{V}_{\text {OUT }} \geq 1.9 \mathrm{~V}$, respectively.

Thus, by simply drawing no more than 3 straight lines, one obtains all of the following immediately:

1. All the necessary design information (e.g., minimum $\mathrm{R}_{\mathrm{L}}$, minimum available IOUT and $\mathrm{V}_{\text {OUT }}$, etc.)
2. Operating characteristics of the circuit as a whole, including the effect of different RON values due to process variations, thus, a better insight into the circuit operation.
3. Most importantly, a guarantee that the circuit will be operating in the safe region, ( $\mathrm{T}_{\mathrm{j}} \leq 150^{\circ} \mathrm{C}$ ).

For different ambient temperatures or for different power considerations, Figure 4 can be applied by properly scaling the IOUT axis. (Note that IOUT $\propto T_{j}-T_{A}$ and $I_{\text {OUT }} \propto P_{D}$ ).


FIGURE 5. Typical IOUT vs Typical Vout
${ }^{*}$ Strictly speaking, RON is a non-linear function of IOUT. A typical RON characteristic at $\mathrm{T}_{\mathrm{j}}=150^{\circ} \mathrm{C}$ is shown in Figure 5. The non-linear characteristic near the origin is due to the fact that the output NPN transistor is not saturated. As soon as saturation is reached (IOUT ~ 150 mA ) the curve becomes a straight line which extrapolates back to the origin. For practical design purposes, it is sufficient to consider RON as a linear function of IOUT.
** Note that as the operating point on the load line moves away from the $\mathrm{P}_{\mathrm{D}}=0.57 \mathrm{~W}$ curve, laway from the tangent point in this case), the actual junction temperature drops. Therefore, at point A , for example, the device is actually running cooler than $\mathrm{T}_{\mathrm{j}}=150^{\circ} \mathrm{C}$, even in the worst case. Hence, RON value drops below $18 \Omega$ and the actual operating point is slightly different from $A$.

To further simplify the design, a family of such curves has been generated as shown in Figure 6. Each of these curves corresponds to a particular $\mathrm{T}_{A}$ and $\mathrm{P}_{\mathrm{D}}$ (per driver) as indicated, and similar to the $P_{D}=0.57 \mathrm{~W}$ curve in Figure 4, is generated from (6) by using appropriate $\mathrm{T}_{\mathrm{A}}$ values. The application of these curves is illustrated as follows:

## Example 1

1. In Figure 3, assume that the two drivers in the MM74C908 package are to operate under identical conditions. Find minimum $R_{L}$ at $T_{A}=25^{\circ} \mathrm{C}, 45^{\circ} \mathrm{C}$, $65^{\circ} \mathrm{C}$ and $85^{\circ} \mathrm{C}$ for both $\mathrm{V}_{\mathrm{CC}}-\mathrm{V}_{\mathrm{L}}=5 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{CC}}-$ $V_{L}=10 \mathrm{~V}$.

Then plot $R_{L}($ MIN $)$ vs $T_{A}$.
a) $V_{C C}-V_{L}=5 V$

By constructing the load lines tangent to the curves for $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, 45^{\circ} \mathrm{C}, 65^{\circ} \mathrm{C}$ and $85^{\circ} \mathrm{C}$, $\mathrm{R}_{\mathrm{L}}(\mathrm{MIN})$ for each case can be obtained through the vertical coordinate for the intersection points as shown in Figure 6. These are calculated in Table I.

Note that the same results (within graphical error) can be obtained analytically by letting $\mathrm{dR}_{\mathrm{L}} /$ $\mathrm{dR}_{\mathrm{ON}}=0$. It can be shown that

$$
\begin{equation*}
R_{L(M I N)}=\frac{\left(V_{C C}-V_{L}\right)^{2}}{4 X(\text { Max Power Per Driver })} \tag{8}
\end{equation*}
$$

b) $V_{C C}-V_{L}=10 \mathrm{~V}$

The $R_{L}(M I N)$ given in (8) may not be a true minimum if the tangent point does not fall inside the specified RON region. The actual $\mathrm{R}_{\mathrm{L}}$ (MIN) can be obtained as shown in Figure 7. The calculations and results are given in Table II.

Note that the $R_{L}(M I N)$ values in Table II are lower than those given by (8). This corresponds to the section on each of the 4 load lines in Figure 7 which extends beyond the power limit curve at each associated temperature. However, this section on each load line is outside the specified RON range. Within the RON range, load lines are below the power limits; therefore, safe operation is guaranteed.

The $R_{L}\left(\right.$ MIN ) vs $T_{A}$ plot is as shown in Figure 8.

All the curves generated so far are restricted to $\mathrm{P}_{\mathrm{D}} \leq 0.57 \mathrm{~W}$ due to our simplifying assumption that both drivers are operating identically. In Figure 9 a few more curves are added to account for the general situation in which only the restriction $\mathrm{P}_{\mathrm{DA}}+\mathrm{PDB} \leq 1.14 \mathrm{~W}$ is required, (i.e., PDA can be different from $P_{D B}$ ). Application of Figure 9 is illustrated as follows:

TABLE $I$.

| $\mathrm{T}_{\text {A }}$ | $25^{\circ} \mathrm{C}$ | $45^{\circ} \mathrm{C}$ | $65^{\circ} \mathrm{C}$ | $85^{\circ} \mathrm{C}$ |
| :---: | :---: | :---: | :---: | :---: |
| IOUT @ D1, 2, 3, 4 (mA) | 450 | 375 | 310 | 240 |
| $R_{\text {L }}($ MIN $)=\frac{5}{I_{\text {OUT @ }} \text { (1, 2, 3,4 }}(\Omega)$ | 11.1 | 13.3 | 16.1 | 20.8 |

TABLE II.

| $\mathrm{T}_{\mathrm{A}}$ |  |  |  |  |
| :--- | :--- | :--- | :--- | :--- |
| $\mathrm{I}_{\text {OUT }} @ \mathrm{D} 1,2,3,4(\mathrm{~mA})$ | $25^{\circ} \mathrm{C}$ | $45^{\circ} \mathrm{C}$ | $65^{\circ} \mathrm{C}$ | $85^{\circ} \mathrm{C}$ |
| $\mathrm{R}_{\mathrm{L}(\mathrm{MIN})}=\frac{10}{\text { IOUT @ D1, 2,3,4}}$ | 261 | 230 | 197 | 166 |





FIGURE 8

In Figure 3, assume that driver A has to deliver 200 mA to its load while driver $B$ needs only 100 mA . Design $R_{L A}$ and $R_{L B}$ for $V_{C C}-V_{L}=5 \mathrm{~V}$.

By inspection of Figure 4, units with high RON values will not be able to deliver 200 mA . However, since section $B$ does not need the same amount of drive, we can reduce the power consumed in this section to compensate for the higher power ( $>0.57 \mathrm{~W}$ ) required in section $A$.

The design procedure follows:

## Section A

1. Draw a load line intersecting $\mathrm{RON}=18 \Omega$ line at IOUT $=200 \mathrm{~mA}$.
2. This load line intersects the IOUT axis at IOUT $=$ 710 mA and is tangent to $\mathrm{P}_{\mathrm{DA}} \simeq 0.9 \mathrm{~W}$ curve, thus $R_{\mathrm{LA}} \cong 5 \mathrm{~V} / 710 \mathrm{~mA}=7.1 \Omega$ will guarantee both PDA $\leq 0.9 \mathrm{~W}$ and I OUTA $\geq 200 \mathrm{~mA}$.

## Section B

1. Draw a load line intersecting $\mathrm{RON}=18 \Omega$ line at IOUT $=100 \mathrm{~mA}$.
2. Similar to (2) above, it is seen immediately that $R_{\text {LB }} \cong 5 \mathrm{~V} / 150 \mathrm{~mA}=33.3 \Omega$ will guarantee IOUTB $\geq$ 100 mA and $\mathrm{PDB} \leq 0.18 \mathrm{~W}$.

Since $P_{D A}+P_{D B} \leq 0.9+0.18<1.14 W$

$$
\begin{aligned}
& \mathrm{R}_{\mathrm{LA}}=7.1 \Omega \\
& \mathrm{R}_{\mathrm{LB}}=33.3 \Omega
\end{aligned}
$$

satisfy all the requirements in this problem.
The design in Example 2 illustrated the simple and straight-forward use of the curves and the result meets all the problem requirements. However, it should be noted that there is not much design margin left for tolerance in resistances and other circuit parameters. The reason is obvious-we are pushing at the power limit of the MM74C908 package-and the solutions are simple:
a) Increase $V_{C C}$ supply
b) Use the higher power package MM74C918.

The design for higher $\mathrm{V}_{\mathrm{CC}}$ is identical to that in Example 2 and will not be repeated here.

For the 14 -lead higher power (2.27W) MM74C918, $\theta_{\mathrm{jA}}=55^{\circ} \mathrm{C} / \mathrm{W}$, this is exactly half that of the 8 -lead MM74C908. Therefore, by scaling the IOUT axis by a factor of 2, the same family of curves in Figure 9 can be applied directly. This is shown in Figure 10. (Note that the slope of the RON $=18 \Omega$ line has been adjusted to the new scale).


FIGURE 10

By drawing the same load lines, it is found that:
$R_{L A} \cong 5 \mathrm{~V} / 710 \mathrm{~mA}=7.1 \Omega$
guarantees $\mathrm{PDA}_{\mathrm{DA}} \leq 0.9 \mathrm{~W}$
and
$R_{\mathrm{LB}} \cong 5 \mathrm{~V} / 150 \mathrm{~mA}=33.3 \Omega$
guarantees $\mathrm{P}_{\mathrm{DB}} \leq 0.18 \mathrm{~W}$

$$
\mathrm{P} \mathrm{DA}+\mathrm{P} \mathrm{~PB} \leq 1.08 \mathrm{~W}
$$

which is way below the maximum power 2.27 W available. Therefore, both R RA and RLB can be lowered to account for tolerance in the resistors. Consider specifically the following example:

## Example 3

Assume driver A, B of the MM74C918 have to deliver 250 mA and 150 mA , respectively, to its load. Design $R_{L A}$ and $R_{L B}$ at $V_{C C}-V_{L}=10 \mathrm{~V}$.

## Driver A

1. In Figure 11, draw the load line intersecting $\mathrm{R}_{\mathrm{ON}}=$ $18 \Omega$ at IOUT $=250 \mathrm{~mA}$.
2. This load line intersects the IOUT axis at 450 mA . Thus, by inspection $R_{\mathrm{LA}} \cong 10 \mathrm{~V} / 450 \mathrm{~mA} \cong 22.2 \Omega$ guarantees PDA $\leq 1.14 \mathrm{~W}$.

## Driver B

1. Draw the load line intersecting RON $=18 \Omega$ at IOUT $=150 \mathrm{~mA}$.
2. This load line intersects the IOUT axis at 210 mA . Thus, by inspection $R_{\mathrm{LB}} \cong 10 \mathrm{~V} / 210 \mathrm{~mA}=47.6 \Omega$ guarantees $\mathrm{PDB} \leq 0.4 \mathrm{~W}$.

Since $\operatorname{PDA}+\mathrm{PDB}_{\mathrm{D}} \leq 1.14+0.4=1.8 \mathrm{~W}$, while the package is capable of delivering 2.27 W , both $R_{\mathrm{LA}}$ and RLB can be lower than the above values and the circuit still operates safely. By picking the closest standard resistance values:

$$
\begin{aligned}
& R_{\mathrm{LA}}=20 \Omega \\
& \mathrm{R}_{\mathrm{LB}}=43 \Omega
\end{aligned}
$$

For 5\% tolerance in these values,

$$
\begin{aligned}
& 19 \Omega \leq R_{\mathrm{LA}} \leq 21 \Omega \\
& 40.85 \Omega \leq \mathrm{R}_{\mathrm{LB}} \leq 45.15 \Omega
\end{aligned}
$$

Thus:

$$
\operatorname{IOUTA}(\mathrm{MIN}) \geq \frac{10 \mathrm{~V}}{18 \Omega+21 \Omega}=256.4 \mathrm{~mA}>250 \mathrm{~mA}
$$

$$
\operatorname{IOUTB}(\mathrm{MIN}) \geq \frac{10 \mathrm{~V}}{18 \Omega+45.15 \Omega}=158.3 \mathrm{~mA}>150 \mathrm{~mA}
$$

$$
\operatorname{PDA}(\mathrm{MAX}) \leq\left(\frac{10 \mathrm{~V}}{18 \Omega+19 \Omega}\right)^{2} \cdot 18 \Omega=1.31 \mathrm{~W}
$$

$$
\mathrm{PDB}(\mathrm{MAX}) \leq\left(\frac{10 \mathrm{~V}}{18 \Omega+40.85 \Omega}\right)^{2} \cdot 18 \Omega=9.52 \mathrm{~W}
$$

$$
\left.\mathrm{PDA}_{\mathrm{DAX}}\right)+\mathrm{PDB}_{\mathrm{D}}(\mathrm{MAX}) \leq 1.31+0.52<2.27 \mathrm{~W}
$$

Therefore:

$$
\begin{aligned}
& R_{\mathrm{LA}}=20 \Omega(1.5 \mathrm{~W}, 5 \%) \\
& R_{\mathrm{LB}}=43 \Omega(1 \mathrm{~W}, 5 \%)
\end{aligned}
$$

will guarantee satisfactory performance of the circuit.

$\mathrm{V}_{\text {CC }}-\mathrm{V}_{\text {OUT }}(\mathrm{V})$
FIGURE 11

Like most other drivers, the MM74C908, MM74C918 can be used to drive relays, lamps, speakers, etc. These are shown in Figure 12. (To suppress transient spikes at turn-off, a diode as shown as Figure 12a is recommended at the relay coil or any other inductive load.)

However, the MM74C908, MM74C918 offers a unique CMOS feature that is not available in drivers from other logic families-extremely low standby power. At $\mathrm{V}_{\mathrm{CC}}=$

15 V , power dissipation per package is typically 750 nW when the outputs are not drawing current. Thus, the drivers can be sitting out on line (a telephone line, for example) drawing essentially zero current until acti-vated-an ideal feature for many applications.

The dual feature and the NAND function of the driver design can also be used to advantage as shown in the following applications:


FIGURE 12a. Relay Driver


FIGURE 12b. Lamp Driver


FIGURE 12c. Speaker Driver

In Figure 13, the 2 drivers in the package are connected as a Schmitt trigger oscillator, where R1 and R2 are used to generate hysteresis. R3 and C are the inverting feedback timing elements and R4 is the pull-down load for the first driver. Because of its current capability, the
circuit can be used to drive an array of LEDs or lamps. If resistor R4 is replaced by an LED (plus a current limiting resistor), the circuit becomes a double flasher with the 2 LEDs flashing out of phase. This is shown in Figure 14.


FIGURE 13. High Drive Oscillator/Flasher


FIGURE 14. Out of Phase Double Flasher

Another oscillator circuit using only $1 / 2$ of the package and 4 passive components is shown in Figure 15. Assume $\mathrm{V}_{\mathrm{I}}$ is slightly below the input trip point, the driver is "ON" and charging both $V_{O}$ and $V_{1}$ until $V_{1}$ reaches the trip point, $\mathrm{V}_{\mathrm{T}}$, when the driver starts to turn "OFF". $V_{O}$ can be made much higher than $V_{1}$ at this instance by adjusting the component values such that $R_{f} C_{f} \gg$ $\left(R_{O N} \| R_{L}\right) C_{L}$. Since $V_{O}$ is higher than $V_{I}, V_{l}$ is still going up, although the driver is "OFF" and $\mathrm{V}_{\mathrm{O}}$ is ramping down. The rising $\mathrm{V}_{\mathrm{l}}$ will eventually equal to
the falling $V_{O}$, and then start discharging. Then, both $V_{1}$ and $V_{O}$ discharge until $V_{I}$ hits the trip point, $V_{T}$, again, when the driver is turned "ON", charging up $\mathrm{V}_{\mathrm{O}}$ and subsequently $\mathrm{V}_{\text {I }}$ to complete a cycle.

This oscillator is ideal for low cost applications like the 1 -package siren shown in Figure 16, where 1 oscillator is used as a VCO while the other is generating the voltage ramp to vary the frequency at the VCO output.


FIGURE 15. Single Driver Oscillator


FIGURE 16. Low Cost Siren

The NAND functions at the input can also be used to reduce package count in applications where both high


FIGURE 17. High Drive RS Latch

# CMOS A/D Converter Chips Easily Interface to 8080A Microprocessor Systems 

## SUMMARY

This paper describes techniques for interfacing National Semiconductor's new ADC3511 and ADC3711 microprocessor compatible analog-to-digital converter chips to 8080 A microprocessor systems. The hardware interface and the software interrupt service routine will be described for single and multiple $A / D$ converter data acquisition systems.

## INTRODUCTION

The recent introduction of monolithic digital voltmeter chips has encouraged designers to consider their use as analog-to-digital converters in data acquisition systems. While the high accuracy afforded at low cost was attractive, certain difficulties in applying these devices in digital systems were encountered. Most of these difficulties were due to the DVM chip's output structure being oriented towards driving 7 -segment displays with internally generated digit scanning rates. National Semiconductor has recently introduced a family of monolithic CMOS A/D converters - two of these devices are directed towards LED display DPM and DVM applications (ADD3501 3 1/2-digit DPM and ADD3701 33/4-digit DPM) while the other two (ADC3511 3 1/2digit A/D and ADC3711 3 3/4-digit A/D) have addressable $B C D$ outputs. These last two devices allow easy interface to microprocessor and calculator-oriented (COPS) systems.

Single or multiple channel monitoring of physical variables can be achieved with high accuracy despite the lack of complexity and low overall cost.

## A/D CONVERSION

All $A / D$ converters in this family operate from a single 5 V supply and convert inputs from 0 to $\pm 2 \mathrm{~V}$. The converters use a pulse-width modulation technique which requires no precision components and exhibits low offset, low drift, high linearity and no rollover error.. An additional advantage is that the voltage reference is of the same polarity as the supply.

Two resolutions are offered: the $31 / 2$-digit types divide the input into 2,000 counts plus sign, while the $33 / 4$ digit types provide 4,000 counts plus sign which is roughly equivalent to the resolution of a 12 -bit plus sign binary converter. The $31 / 2$-digit converters require 200 ms per conversion; 3 3/4-digit types require 400 ms :

The converters handle negative inputs by internally switching the inputs and forcing the sign bit low. While this technique allows conversion of positive and negative inputs with only a single supply, the inputs must be floating with respect to the supply return. Without a floating supply, only positive voltages may be converted.

The basic converter is shown in Figure 1. The actual conversion technique is described in Appendix A.


FIGURE 1. Basic A/D Converter

The ADC3511 and ADC3711 present the output data in BCD form on a single 4 -line output port, plus a separate sign output. The desired digit is selected by a 2 -bit address which is latched by a high level at the Digit Latch Enable input (DLE); a low level at DLE allows flow thru operation. Since the output is BCD, it is compatible with many standard instruments and can easily be converted into binary by the processor if this format should be desired. Overrange inputs are indicated by a hexidecimal "EEEE" plus an Overflow output.

A new conversion is begun by a positive pulse or high level at the Start Conversion (SC) input. The analog section of the converter continuously tracks the analog input. The Start Conversion command controls only the transfer of new data to the output latches, consequently the delay from the SC pulse to the Conversion Complete (CC) signal may vary from several milliseconds to several hundred milliseconds. In interrupt driven systems the delay is no problem, since the processor does not execute delay instructions while waiting for the data. However, if in-line or program I/O is used where the program waits for the data to be ready, the maximum delay between SC and CC must be programmed into the wait routine. This type of I/O is therefore not as efficient as interrupt I/O.

The CC output goes low immediately after the SC pulse. At the end of a conversion, CC goes high and remains high until a new conversion is initiated. Continuous conversion operation is obtained by tying the SC input to $V_{C C}$.

## REFERENCE VOLTAGE

The 2.000 V reference is derived from the LM336, a recently announced monolithic reference which provides 2.5 V with low drift at low cost. This active reference is adjusted for minimum thermal drift of about $20 \mathrm{ppm} /{ }^{\circ} \mathrm{C}$ by using a third terminal on the device to adjust its output to 2.490 V .

Total reference current consumption is low, as the LM336 requires only 1 mA of bias current, and the resistor divider about 2 mA . The reference circuit is


FIGURE 2. A/D Converter Reference. The 10k Pot is Adjusted to a Voltage of 2.49 V on the Output; at this Voltage Minimum Drift Occurs. The Reference can Supply up to 8 A/D Converters.
shown in Figure 2. One reference can be used for many A/D's. The value of the upper series resistor R1 depends on the number of converters used.

## A SINGLE CHANNEL CONVERTER

A complete $A / D$ port is seen in Figures 3 and 4. Figure 3 shows a Dual Polarity converter and Figure 4 a Positive Only Polarity converter. Each port contains an A/D converter, TRI-STATE ${ }^{\circledR}$ bus driver, and 2 gates to control I/O. This A/D port is easily used in single or multichannel systems. In multichannel systems a converter is used on every channel allowing digital multiplexing of the outputs.

Data from the A/D converter in a single channel system is easily processed using an OUT command to start a conversion and IN commands to read the data after the microprocessor has been interrupted by a Conversion Complete.

As seen in Figure 5, a single channel A/D port uses a 6 -bit bus comparator to decode its assigned peripheral address from the lower address bits of the 8080 A address bus.

When an interrupt is received, the present status of the processor is stored on the stack memory by a series of push commands. The interrupt is serviced by reading digit 4 (MSD) into the processor and checking the overflow bit. If the overflow bit is high, the converter input has exceeded its range and an error signal i:, generated, indicating that scaling must be done to attenuate the input signal. If the OFL is low, the sign bit is then checked to determine the polarity of the conversion. If the sign bit is low, a " 1 " is added to the MSB of digit 4. Since this bit would normally be low, (maximum converter range allows MSB $\leq 3$ or 0011) a " 1 " in this position is used to denote a negative input voltage. The 4 bits of digit 4 which now include the sign are shifted into the upper half of the first byte and the 4 bits of digit 3 are packed into the lower half. Similarly, digits 2 and 1 are packed into the second byte and both bytes stored in memory.

Figure 6 and routine 1 are the flow chart and assembly language routine used to implement this action.

## 8-CHANNEL A/D WITH SOFTWARE PRIORITY

The basic A/D port can easily be expanded to multiple channel systems. An 8-channel system is seen in Figure 7. This system interrupts the processor when one of the Conversion Complete outputs goes high. The processor saves the current status and reads the status word of the $A / D$ system. The status word is then compared to a priority table. Each level in the table corresponds to a priority level with high priority converters which are first in the table. If 2 or more converters have the same priority and are ready at the same time, the converter with the highest number gets serviced first.

The program determines which service routine to use by the bit position of " 1 ' $s$ " in the status word. The routine loads the address pointer to digit 4 of the selected converter. The program then calls a subroutine which
goes through the process of checking overflow, sign and packs 4 BCD digits into 2 bytes. These 2 bytes are then stored in a table in the memory directly above the converter addresses. After a channel is serviced, the
original processor status is restored and the interrupt enabled. If additional channels need service, they immediately interrupt so the new status word is then read and a new priority established.


FIGURE 3. Dual Polarity A/D Requires that Inputs are Floating with Respect to the Supply. Input Range is $\pm 1.999 \mathrm{~V}$.


FIGURE 4. Positive Polarity A/D Operating from 5V Supply. Input Range is +1.999 V .


FIGURE 5. Single Channel A/D Interface with Peripheral Mapped I/O


FIGURE 6. Flow Chart for Single Channel A/D Converter

| LABEL | OPCODE | OPERAND | COMMENT | LABEL | OPCODE | OPERAND | COMMENT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ADIS: | PUSH | PSW | ; A/D interrupt service |  | IN RAL | ADD 2 | ; delay <br> ; rotate |
|  | PUSH | H | ; save |  | RAL |  | ; into |
|  | PUSH | B | ; current status |  | RAL |  | ; upper |
|  | IN | ADD 4 | ; input $A / D$ digit 4 |  | RAL |  | ; 4 bits |
|  | IN | ADD 4 | ; delay |  | ANI | FO | ; mask lower bits |
|  | ORA |  | ; reset carry |  | MOV | C, A | ; save in C |
|  | RAL |  | ; rotate OFL thru |  | IN | ADD 1 | ; in digit 1 |
|  |  |  | carry |  | IN | ADD 1 | ; delay |
|  | JC | OFL | ; overflow condition |  | ANI | OF | ; mask upper bits |
|  | RAL |  | ; rotate sign thru |  | OR | C | ; pack |
|  |  |  | carry |  | MOV | C, A | ; save in C |
|  | JC | PLUS | ; positive input |  | LXI | H, ADMS | ; load ptr to A/D |
|  | ORI | 20 H | ; OR 1 into MSB, |  |  |  | Mem, space |
|  |  |  | neg input |  | MOV | M, C | ; save C in memory |
| PLUS: | RAL |  | ; shift |  | INX | H | ; point next |
|  | RAL |  | ; into position |  | MOV | M, B | ; save B in memory |
|  | ANI | FO | ; mask lower bits |  | OUT | ADD 1 | ; start new conver- |
|  | MOV | BA | ; save in B |  |  |  | sion |
|  | IN | ADD 3 | ; input digit 3 | 1 | POP | B | ; restore |
|  | IN | ADD 3 | ; delay |  | POP | H | ; previous |
|  | ANI | OF | ; mask higher bits |  | POP | PSW | ; status |
|  | OR | B | ; pack into B-* |  | El |  | ; enable interrupts |
|  | MOV | B, A | ; save in B |  | RET |  | ; return to main |
|  | IN | ADD 2 | ; input digit 2 |  |  |  | program |

Routine 1. Single Channel Interrupt Service Routine


FIGURE 7. 8-Channel A/D System with Maskable Priority Interrupt Using Memory Mapped I/O


FIGURE 8. Flow Charts of A/D Routines


FIGURE 8. Flow Charts of A/D Routines (Continued)

| LABEL | OPCODE | OPERAND | COMMENT |  | LABEL | OPCODE | OPERAND | COMMENT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| IAD: | PUSH | PSW | ; interrupt from A/D |  |  | XCGH |  | ; exchange DE, HL |
|  | PUSH | H | ; save H \& L on stack |  |  | PCHL |  | ; jump to input routine |
|  | PUSH | B | ; save $B \& C$ on stack | 1 | INAD1: | LXI | H. AD1 | ; pickup pointer to A/D 1 |
|  | PUSH | D | ; save D \& E on stack |  |  | CALL | ADIN | ; call common input routine |
|  | LXI | H, ADWD | ; pickup A/D status |  |  | MOV | M, A | ; start new conversion |
|  |  |  | word |  |  | JMP | DONE | ; all done |
|  | $\begin{aligned} & \text { MOV } \\ & \text { LXI } \end{aligned}$ | 6, M <br> H, PRTBL | ; move word into B ; pickup priority tbl |  | INAD2: | LXI | H, AD2 | ; pickup pointer to A/D 2 |
|  |  |  | pointer |  |  | CALL | ADIN | ; call input routine |
| TEST: | MOV | A, B | ; place status word in accum. |  |  | MOV | $\mathrm{M}, \mathrm{A}$ | ; start new conversion |
|  | ANA | M | ; mask with priority table |  |  | JMP | DONE | ; all done |
|  | JNZ | FIND | ; match jump to Find |  |  | . |  |  |
|  | INX | H | ; point to lower |  | DONE: | POP | D | ; restore D |
|  |  |  | priority |  |  | POP | B | ; restore B |
|  | JMP | TEST | ; try again |  |  | POP | H | ; restore H |
| FIND: | LXI | H, RTBL | ; pickup routine tbl pointer |  |  | $\begin{aligned} & \text { POP } \\ & \text { EI } \end{aligned}$ | PSW | ; restore PSW <br> ; enable interrupts |
|  | ORA | A | ; reset carry |  |  | RET |  | ; return to main |
| GTBIT: | RAR |  | ; rotate thru carry |  |  |  |  | program |
|  | JC | GTAD | ; bit was found |  | PRTBL: | DB | 04H | ; 0000C100 AD3 |
|  | INX | H | ; point to |  |  |  |  | highest priority |
|  | INX | H | ; next routine |  |  | DB | 03H |  |
|  | JMP | GTBIT | ; try again |  |  |  |  | AD1 next priority |
| GTAD: | MOV | E, M | ; move first byte into $E$ |  |  | . |  |  |
|  | INX | H | ; point to next byte |  |  | . |  |  |
|  | MOV | D, M | ; move second byte into D |  |  | , |  |  |

Routine 2. 8-Channel Interrupt Service Routine with Software Priority

| LABEL | OPCODE | OPERAND | COMMENT | LABEL | OPCODE | OPERAND | COMMENT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PRTBL: | DB | 10 H | ; 00010000 AD5 lowest priority |  | MOV | B, A | ; save in B |
|  |  |  |  |  | DCR | H | ; point to LSD + 1 |
| RTBL: | DW | 1000 H | ; routine for A/D 1 |  | MOV | A, M | ; input LSD + 1 |
|  | DW | 100 CH | ; routine for A/D 2 |  | MOV | A, M | ; delay |
|  | . |  |  |  | RAL |  | ; rotate |
|  | . |  |  |  | RAL |  | ; into |
|  |  |  |  |  | RAL |  | ; upper |
|  | DW | 1060H | ; routine for A/D 8 |  | RAL |  | ; 4 bits |
| ADIN: | MOV | A, M | ; input MSD plus |  | ANI | FO | ; mask lower bits |
|  |  |  | OFL \& SIGN |  | MOV | C, A | ; save in C |
|  | MOV | A, M | ; delay |  | DCR | H | ; point to LSD |
|  | ORA | A | ; reset carry |  | MOV | A, M | ; input LSD |
|  | RAL |  | ; rotate left thru |  | MOV | A, M | ; delay |
|  |  |  | carry, OFL |  | ANI | OF | ; mask upper bits |
|  | JC | OFL | ; jump to overflow |  | OR | C | ; pack |
|  |  |  | if set |  | MOV | C, A | ; save in C |
|  | RAL |  | ; rotate left thru |  | SHLD | TEMP | ; store HL in temp |
|  |  |  | carry, sign |  | MOV | A, L | ; move L in accum. |
|  | JC | PLUS | ; jump to plus if set |  | ACI | 64 | ; generate lower |
|  | OR1 | 20 H | ; OR1 into BCD, |  |  |  | address |
|  |  |  | MSB for minus |  | MOV | L, A | ; above memory |
| PLUS: | RAL |  |  |  |  |  | mapped |
|  | RAL | FO |  |  | MOV | A, H | ; converter addresses |
|  | ANI |  | ; mask lower order |  | ACI | 0 | ; include carry |
|  |  |  | bits |  | MOV | H, A | ; to upper bits |
|  | MOV | B, A | ; save in B |  | MOV | M, C | ; store C |
|  | DCR | H | ; point to MSD-1 |  | INX | H | ; then |
|  | MOV | A, M | ; input MSD-1 |  | MOV | M, B | ; store B |
|  | MOV | A, M | ; delay |  | LHLD | TEMP | ; retrieve HL |
|  | ANI | OF | ; mask higher 4 bits |  | RET |  | ; return |
|  | OR | B | ; pack MSD and MSD-1 |  |  |  |  |

Routine 2. 8-Channel Interrupt Service Routine with Software Priority (Continued)

## ADJUSTMENT AND TESTING

Adjustment and testing of a single channel $A / D$ is done by monitoring the memory space where the interrupt routine stores the data word. The microprocessor is forced to loop around a section of program with interrupts enabled. As the input voltage of the converter is changed, this data word should also change as the converter updates it. A precision voltage reference is connected to the input of the $A / D$ and incremental voltage steps are applied. The A/D data word should also change according to the voltage steps.

At full-scale input voltage, the data word should be at its maximum value. If not, check the full-scale adjust on the $A / D$ by adjusting it so the OFL bit goes high when the input is exactly 2.000 V .

Multichannel systems are more difficult to check. Start by individually checking the full-scale adjustments so the converters overflow at 2.000 V . Check the software priority routine by forcing all status bits of the status word high. This corresponds to all converters being ready at the same time, a very unlikely worst-case condition. The microprocessor should respond by outputting the address of all 4 digits of the A/D port with the highest priority along with the memR strobes, then with a memW strobe to start a new conversion. The next highest priority converter should then receive its addresses and $\overline{m e m R}$ strobes and so on down the line.

Once the priority routine has been debugged, each data word is monitored as the input to its converter is adjusted. Since a common input routine is used, once 1 channel operates, all the other channels should also.

Debugging may most easily be done by single stepping through the program at these critical areas. No timing problems should be encountered since the $A / D$ port appears to be a standard peripheral or memory. In the ADC3511 and ADC3711 the desired output is merely addressed the same as a memory location.

The memory requirements of the interface depends, of course, on the complexity of the system. The single channel converter requires approximately 60 bytes of program storage plus 2 bytes for data storage and 4 peripheral addresses.

The multichannel system requires about 40 bytes for the priority routine and 10 bytes of program for each converter routine. The common input routine requires about 50 bytes of program and is used by all the converter routines in the form of a subroutine.

Memory mapped I/O causes 64 memory locations to be used to input an 8 -channel system. The data space is located directly above the address space for the converters and 16 memory locations are used to store the data for 8 converters.

## CONCLUSION

The ADC3511 and ADC3711 microprocessor compatible A/D converters eliminate the difficulties previously encountered in applying DPM chips to microprocessor systems. The low parts count and low cost per channel make distributed or remote A/D conversion practical for a variety of data acquisition applications.

## APPENDIX A

## THEORY OF OPERATION

A schematic for the analog loop is shown in Figure A1. The output of SW 1 is either at $V_{\text {REF }}$ or OV, depending on the state of the $D$ flip-flop. If $Q$ is at a high level, $\mathrm{V}_{\text {OUT }}=\mathrm{V}_{\text {REF }}$ and if Q is at a low level $\mathrm{V}_{\text {OUT }}=0 \mathrm{~V}$. This voltage is then applied to the low pass filter comprised of R1 and C1. The output of this filter, VFB, is connected to the negative input of the comparator, where it is compared to the analog input voltage, VIN. The output of the comparator is connected to the D input of the D flip-flop. Information is then transferred from the D input to the Q and $\overline{\mathrm{Q}}$ outputs on the positive edge of clock. This loop forms an oscillator whose duty cycle is precisely related to the analog input voltage, VIN.

An example will demonstrate this relationship. Assume the input voltage is equal to 0.500 V . If the Q output of the $D$ flip-flop is high, then VOUT will equal $V_{R E F}$ (2.000V) and VFB will charge toward 2 V with a time constant equal to R1C1. At some time $\mathrm{V}_{\mathrm{FB}}$ will exceed 0.500 V and the comparator output will switch to OV . At the next clock rising edge, the Q output of the D flip-flop will switch to ground, causing VOUT to switch to $O V$. At this time, $V_{F B}$ will start discharging toward $0 V$ with a time constant R1C1. When $V_{F B}$ is less than 0.5 V , the comparator output will switch high. On the rising edge of the next clock, the Q output of the D flip-flop will switch high and the process will repeat. There exists at the output of SW 1 a square wave pulse train with positive amplitude VREF and negative amplitude $0 V$.

The DC value of this pulse train is:

$$
V_{\text {OUT }}=V_{\text {REF }} \frac{\text { tON }}{\text { tON }+ \text { tOFF }}=V_{\text {REF }} \text { (duty cycle) }
$$

The low pass filter will pass the DC value and then:

```
VFB}=\mp@subsup{V}{\mathrm{ REF (duty cycle)}}{
```

Since the closed loop system will always force VFB to equal $V_{I N}$, we can then say that:

$$
V_{I N}=V_{F B}=V_{\text {REF }} \text { (duty cycle) }
$$

or

$$
\frac{V_{\text {IN }}}{V_{\text {REF }}}=(\text { duty cycle })
$$

The duty cycle is logically ANDed with the input frequency $f I N$. The resultant frequency fequals:

$$
f=(\text { duty cycle }) \times(f, N)
$$

Frequency f is accumulated by counter no. 1 for a time determined by counter no. 2. The count contained in counter no. 1 is then:

$$
\text { count }=\frac{f}{(f / N) / N}=\frac{\left(\text { duty cycle) } \times\left(f_{I N}\right)\right.}{\left(f_{I N}\right) / N}=\frac{V_{I N}}{V_{\text {REF }}} \times N
$$

For the ADC3511 N = 2000.
For the $A D C 3711 \mathrm{~N}=4000$.


Count in Counter No. $1=\frac{f}{f_{I N} / N}=\frac{\text { (duty cycle) } \times f_{I N}}{f_{I N} / N}=\frac{V_{I N}}{V_{\text {REF }}} \times N$
FIGURE A1. Analog Loop Schematic Pulse Modulation A/D Converter

## ELECTRICAL CHARACTERISTICS

ADC3511CC, ADC3711CC $4.75 \leq V_{C C} \leq 5.25 V ;-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}}+85^{\circ} \mathrm{C}, \mathrm{f}_{\mathrm{C}}=5$ conv. $/ \mathrm{sec}$
(ADC3511CC): 2.5 conv./sec (ADC3711CC); unless otherwise specified.

| PARAMETER |  | CONDITIONS | MIN | TYP <br> (Note 2) | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Non-Linearity |  | (Note 3) <br> $V_{\text {IN }}=0-2 V$ Full-Scale <br> $V_{\text {IN }}=0-200 \mathrm{mV}$ Full-Scale |  | $\pm 0.025$ | 0.05 | \% of Full-Scale |
|  |  | -0.05 |  |  |  |
|  |  |  |  |  |  |
|  | Organization Error |  |  | -1 |  | 0 | Counts |
|  | Offset Error |  | V IN $=0 \mathrm{~V},($ Note 4) | -0.5 | 1.0 | 3.0 | $m \mathrm{~V}$ |
|  | Rollover Error |  | -0 |  | 0 | Counts |
| $V_{1 N+} V_{\text {IN }}$ | Analog Input Current | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | -5 | 1 | 5 | $n A$ |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
Note 2: All typicals are given for $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
Note 3: For the ADC3511CC: full-scale $=1999$ counts; therefore, $0.025 \%$ of full-scale $=1 / 2$ counts and $0.05 \%$ of full-scale $=1$ count.
For the ADC3711CC: full-scale $=3999$ counts; therefore, $0.025 \%$ of full-scale $=1$ count and $0.05 \%$ of full-scale $=2$ counts.
Note 4: For full-scale $=2.000 \mathrm{~V}: 1 \mathrm{mV}=1$ count for the $\mathrm{ADC} 3511 \mathrm{CC} ; 1 \mathrm{mV}=2$ counts for the ADC 3711 CC .


FIGURE A2. ADC3511 3 1/2-Digit A/D (*ADC3711 3 3/4-Digit A/D) Block Diagram

## Radiation Hardened CMOS

For many years, military, aerospace and satellite programs have depended on bipolar transistor and integrated circuit technology in the fabrication of airborne systems. Development of bipolar technology is an outgrowth, in part, of avionics and space applications needs. Despite their relatively high immunity or resistance to high levels of both constant and burst radiation in the form of gamma rays, x-rays, cosmic rays, and so on, bipolar devices have one drawback: high power consumption, which adds to the payload of spacecraft and missiles.

In recent years, development of sophisticated space, satellite and military systems, and mission requirements has fostered an active search for a radiation hardened circuit technology that consumes less power and offers a higher degree of circuit integration on a single silicon chip. Development of metal oxide semiconductor (MOS) devices, particularly the complementary MOS (CMOS) type, seemed to promise just such an alternative. But standard CMOS devices, even those qualified to MIL-STD-38510 or JAN standards, are sensitive to relatively low radiation levels. To date, mass producible radiation hardened or resistant CMOS devices have been able to withstand only 105 rads ( Si ), while many space, satellite and missile systems require circuitry resistance levels at least ten times higher, about 106 rads ( Si ), at a minimum. Now, the problem appears to be

National Semiconductor Application Note 208
A. London
D. Matteucci
R. Wang
solved. A complete line of one megarad (106) CMOS logic products using a mass producible radiation hardening fabrication process has been developed, the result of a two-year research effort. Devices ranging in complexity from simple gates to large scale integrated (LSI) random access memories have been hardened to radiation doses of more than 106 rads of constant level gamma radiation (table 1). There are 47 circuits presently available with at least 21 more to be qualified by the end of 1978. To achieve this level of radiation resistance in a mass production CMOS process, major modifications were made in the basic commercial process, relating to gate oxidation, substrate and P-tub surface concentrations, and metallization.

## Bipolar vs CMOS

The inherently higher radiation resistance of bipolar over CMOS devices results from a basic difference in their structures. Bipolar devices are vertical structures. The basic elements - emitter, collector, and base - are laid down vertically, layer upon layer, by diffusion. Current flows through the bulk silicon, some distance below the silicon-silicon dioxide interface. Thus, there is some inherent protection from the interface effects of ionizing radiation in bipolar devices.

CMOS devices are surface effect devices．The equi－ valent operating elements，gate，source and drain， are at the surface，and the flow of current occurs horizontally across the device，very close to the silicon－silicon dioxide interface．Changes in inter－ face parameters created by gamma or x－radiation will have a first order effect on MOS transistor perfor－ mance，in contrast to a second order effect on a bipolar device．Thus the basic physics of CMOS tran－ sistor structures need to be addressed to minimize ionizing radiation effects without substantially impacting performance．

## CMOS Transistor Structure

Complementary MOS，or CMOS，combines two types of MOS devices，P－channel and N －channel structures， as a functioning unit．The lower power dissipation and high stability resulting from this complementary combination is particularly attractive in the design of portable，battery powered，electronic units，or for applications where a battery provides standby power．

MOS structures，both N －and P－types，perform in two modes，enhancement and depletion．In a P－channel enhancement mode MOS device，for example，the gate controls the current flow between the source and drain．In this device，when a negative voltage is applied to the gate with respect to the source，a field is set up across the gate dielectric，producing a positively charged conductive path，a channel， between the source and the drain．This is known as an enhancement mode device because zero gate to source voltage turns off the device．In the alternative mode，depletion，current flows despite the gate voltage being zero，because sufficient field is still present within the gate to induce a conductive path between the device source and drain regions．The N －channel MOS transistor is similar to the P －channel alternative，except that positive voltage applied to the gate with respect to source induces a negatively charged conductive path between source and drain to turn the device on．

Conventional CMOS logic circuits are produced with only enhancement mode N －and P－channel devices． The process is designed to give turn on（threshold） voltage values for both types of devices which insure proper circuit performance．Figure 1 illustrates the cross section of a CMOS structure connected in a simple inverter configuration．To form the standard metal gate CMOS structure，a lightly doped $P$－tub is formed by diffusion into an N－type substrate with the tub becoming the substrate for the N －channel tran－ sistor．The $\mathrm{N}+$ and $\mathrm{P}+$ impurities are diffused into


Figure 1．Cross Section of a CMOS Transistor Structure Connected in a Simple Inverter Configuration
the P－tub and N －substrate to become the N －and P－channel transistors，source and drain regions， respectively．These diffusions also serve as contacting regions to the positively biased N －substrate and the normally grounded P －tub regions （ $\mathrm{V}_{\mathrm{DD}}$ and $\mathrm{V}_{\mathrm{SS}}$ respectively）．

A gate oxide is grown such that a thin film of dielec－ tric oxide material bridges the source／drain regions over the entire circuit．Finally，contact apertures are etched to the source／drain regions and an aluminum film evaporated and etched to form gate electrodes， contacts to device terminals，and interconnection conductor lines．

## Effects of lonizing Radiation

A CMOS transistor＇s radiation resistance is primarily determined by formation of the gate structures in both P－channel and N －channel devices．The gate structures are used to turn the MOS devices on or off； that is，to start or stop a flow of current from the source to the drain．lonizing radiation induces unwanted positive charge into the gate oxide struc－ ture，resulting in lowering the threshold voltage of actual circuit devices and parasitic field oxide devices by values of as much as 30 V or more．In establishing a radiation hardened CMOS process，it is necessary to incorporate processing steps which minimize these radiation induced shifts in critical locations of the IC structure．

The impact of radiation induced oxide charge on operating CMOS devices is to decrease both the N －channel threshold voltage， $\mathrm{V}_{\mathrm{TN}}$ ，and the P－channel threshold voltage， $\mathrm{V}_{\mathrm{TP}}$ ．The most serious problem occurs when sufficient reduction in $V_{\text {TN }}$ occurs to cause the N －channel device to go from enhancement to depletion mode operation．This results in exces－
sive power supply current drain and loss of circuit functionality．The most severe stress on an N －channel device occurs when its gate is positively biased during irradiation．This causes positive charge in the oxide to be driven closer to the $\mathrm{Si}-\mathrm{SiO}_{2}$ interface where it is more effective in causing the P－type substrate surface to become inverted to N －type．

In normal operation，positive bias does not appear between the gate and substrate of P－channel devices since the substrate is already at the most positive circuit potential， $\mathrm{V}_{\mathrm{DD}}$ ．The most severe effect on $P$－channel devices during irradiation often occurs with zero gate to substrate bias．This stress creates． $\mathrm{Si}-\mathrm{SiO}_{2}$ interface states which are capable of holding a positive charge with negative voltage applied to the gate．This increases the absolute value of $\mathrm{V}_{\mathrm{TP}}$ ，but is a much less deleterious effect on the circuit than the $\mathrm{V}_{\mathrm{TN}}$ shift．

## CMOS Process Modification

Gate Oxidation：To minimize both the radiation in－ duced positive oxide charge and formation of $\mathrm{Si}-\mathrm{SiO}_{2}$ interface states，a dry rather than wet oxidation step is used．The gate oxide is thermally grown in a pure oxygen ambient，rather than in a water ambient，as is the case in some metal gate fabrication processes． Moreover，the gate oxide is thermally grown at $1000^{\circ} \mathrm{C}$ ，followed by a nitrogen anneal at $850^{\circ} \mathrm{C}$ ．This cycle has been empirically found to produce oxides having a high degree of resistance to ionizing radiation effects as well as excellent pre－radiation MOS characteristics．＊Why this is so is not known exactly，and is still being studied．The need for thermally growing gate oxides at $1000^{\circ} \mathrm{C}$ in dry oxygen for optimal radiation hardness is one of the more intriguing aspects of this experimentally deduced cycle．
Metallization：A by－product of the E－beam aluminum evaporation process commonly used in commercial IC fabrication is soft $x$－radiation．This radiation


Figure 2． $\mathrm{V}_{\mathrm{TN}}$ vs Dose

[^32]produces the same type of positive charge in the gate oxide and interface states which a radiation hardened oxide should resist．Although these harm－ ful effects in the gate oxide can be removed by a high temperature anneal cycle，subsequent exposure of the oxide to ionizing radiation results in a drastically less radiation resistant structure．Use of a non－ E－beam metallization technique circumvents the problem of high threshold shifts due to irradiation under zero and negative gate bias associated with soft x－ray damage．For this reason，induction heated evaporation of aluminum is used to fabricate radia－ tion hardened CMOS products．
Substrate and P－tub Surface Concentration：The im－ pact of ionizing radiation on $V_{T N}$ and $V_{T P}$ values in a CMOS device is resolved through process modifica－ tion．In anticipation of these threshold voltage shifts， radiation hardened CMOS devices are designed with the initial value of $V_{T N}$ as high as possible and $V_{T P}$ as close to zero as possible without sacrificing pre－ radiation circuit performance．Both the substrate resistivity and the P－tub surface concentration have been modified with the initial value of $\mathrm{V}_{\mathrm{TN}}$ being increased to 1.8 volts from the standard value of 1.3 volts and $V_{T P}$ being changed from the standard－1．7 volts to -1.3 volts．

## Performance Characteristics

Figures 2 and 3 illustrate the variation of post radia－ tion $V_{T N}$ and $V_{T P}$ with dose．The distribution of the $V_{T N}$ and $V_{T P}$ data is found normal both before and after irradiation．The solid line shows the mean value of $\mathrm{V}_{\mathrm{TN}}$（or $\mathrm{V}_{\mathrm{TP}}$ ），and the dashed lines indicate the one standard deviation，$\sigma$ ，value on either side of the mean．This value，for both N －and P －channel devices， remains fairly constant with dose from the unir－ radiated case through 106 rad（ Si ）．The values shown remain well above the $300 \mathrm{mV} \mathrm{V}_{\mathrm{TN}}$ lower limit，which， if penetrated，would lead toward N －channel depletion mode behavior and risk of losing circuit functionality and excessive supply current drain．


Figure 3． $\mathbf{V}_{\mathrm{TP}}$ vs Dose

Figure 4 illustrates the supply quiescent current，$I_{\text {SS }}$ ， variation as a function of dose．Since $I_{s s}$ is a function of die size，curves have been plotted for three levels of integration，SSI，MSI and LSI．In all cases，the leakage level at $106 \mathrm{rad}(\mathrm{Si})$ does not increase by more than an order of magnitude from the initial value．The end point at $106 \mathrm{rad}(\mathrm{Si})$ for LSI of $30 \mu \mathrm{~A}$ is far below the high temperature $\left(125^{\circ} \mathrm{C}\right)$ specification of $600 \mu \mathrm{~A}$ ．The same conclusion can be drawn for MSI and SSI．

Figure 5 illustrates circuit propagation delay， $\mathrm{t}_{\text {PD }}$ ，as a function of dose．The plot，similar to figure 4 ，is divided into three categories（LSI，MSI，SSI）．The propagation delay value at 106 rads（ Si ）for all three categories increased roughly $20-25 \%$ from the initial value，well within desirable operating tolerances．In


Figure 4． $\mathrm{I}_{\mathrm{ss}}$ vs Dose
figures 2 through 5，the biasing conditions during irradiation were： $\mathrm{V}_{D D}=10 \mathrm{~V}, \mathrm{~V}_{\mathbb{I N}}=10 \mathrm{~V}$ ，and $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ ．

## Hardness Assurance and Reliability

A sampling plan has been established to ensure radiation hardness to $10^{5}$ and $10^{6}$ rads，since ionizing radiation degrades IC performance and cannot be used for $100 \%$ screening．In addition，an intensive program to evaluate the reliability characteristics of radiation hardened CMOS circuits is underway． 476 devices of the CD4001 AD／RH，CD4011 AD／RH，and MM54C200D／RH types have been tested and have operated for over 800,000 hours without a failure． This corresponds to a failure rate less than or equal to $0.125 \% / 1000$ hours at $125^{\circ} \mathrm{C}$ with a $60 \%$ confidence level．


Figure 5． $\mathrm{t}_{\mathrm{PD}}$ vs Dose

# Using the ADC0808/ADC0809 8-Bit $\mu$ P Compatible AJD Converters with 8-Channel Analog Multiplexer 

## INTRODUCTION

The ADC0808/ADC0809 Data Acquisition Devices (DAD) implement on a single chip most of the elements of the standard data acquisition system. They contain an 8 -bit A/D converter, 8 -channel multiplexer with an address input latch, and associated control logic. These devices provide most of the logic to interface to a variety of microprocessors with the addition of a minimum number of parts.
These circuits are implemented using a standard metalgate CMOS process. This process is particularly suitable to applications where both analog and digital functions must be implemented on the same chip.
These two converters, the ADC0808 and ADC0809, are functionally identical except that the ADC0808 has a total unadjusted error of $\pm 1 / 2$ LSB and the ADC0809 has an unadjusted error of $\pm 1$ LSB. They are also related to their big brothers, the ADC0816 and ADC0817 expandable 16 channel converters. All four converters will typically do a conversion in $\sim 100 \mu$ s when using a 640 kHz clock, but can convert a single input in as little as $\sim 50 \mu \mathrm{~s}$.

### 1.0 FUNCTIONAL DESCRIPTION

The ADC0808/ADC0809, shown in Figure 1, can be functionally divided into 2 basic subcircuits. These two subcircuits are an analog multiplexer and an A/D converter. The multiplexer uses 8 standard CMOS analog switches to provide for up to 8 analog inputs. The switches are selectively turned on, depending on the data latched into a 3-bit multiplexer address register.

The second function block, the successive approximation A/D converter, transforms the analog output of the multiplexer to an 8 -bit digital word. The output of the multiplexer goes to one of two comparator inputs. The other input is derived from a 256 R resistor ladder, which is tapped by a MOSFET transistor switch tree. The converter control logic controls the switch tree, funneling a particular tap voltage to the comparator. Based on the result of this comparison, the control logic and the successive approximation register (SAR) will decide whether the next tap to be selected should be higher or lower than the present tap on the resistor ladder. This algorithm is executed 8 times per conversion, once every 8 clock periods, yielding a total conversion time of 64 clock periods.
When the conversion cycle is complete the resulting data is loaded into the TRI-STATE ${ }^{\oplus}$ output latch. The data in the output latch can then be read by the host system any time before the end of the next conversion. The TRI-STATE capability of the latch allows easy interface to bus oriented systems.

The operation of these converters by a microprocessor or some control logic is very simple. The controlling device first selects the desired input channel. To do this, a 3-bit channel address is placed on the A, B, C input pins; and the ALE input is pulsed positively, clocking the address into the multiplexer address register. To begin the conversion, the START pin is pulsed. On the rising edge of this pulse the internal registers are cleared and on the falling edge the start conversion is initiated.


FIGURE 1. ADC0808/ADC0809 Functional Block Diagram

[^33]As mentioned earlier, there are 8 clock periods per approximation. Even though there is no conversion in progress the ADC0808/ADC0809 is still internally cycling through these 8 clock periods. A start pulse can occur any time during this cycle but the conversion will not actually begin until the converter internally cycles to the beginning of the next 8 clock period sequence. As long as the start pin is held high no conversion begins, but when the start pin is taken low the conversion will start within 8 clock periods.

The EOC output is triggered on the rising edge of the start pulse. It, too, is controlled by the 8 clock period cycle, so it will go low within 8 clock periods of the rising edge of the start pulse. One can see that it is entirely possible for EOC to go low before the conversion starts internally, but this is not important, since the positive transition of EOC, which occurs at the end of a conversion, is what the control logic is looking for.
Once EOC does go high this signals the interface logic that the data resulting from the conversion is ready to be read. The output enable (OE) is then raised high. This enables the TRI-STATE outputs, allowing the data to be read. Figure 2 shows the timing diagram.

### 2.0 ANALOG INPUTS

### 2.1 Ratiometric Inputs

The arrangement of the $\operatorname{REF}(+)$ and $\operatorname{REF}(-)$ inputs is intended to enable easy design of ratiometric converter systems. The REF inputs are located at either end of the 256R resistor ladder and by proper choice of the input voltages several applications can be easily implemented.

Figure 3 shows a typical input connection for ratiometric transducers. A ratiometric transducer is a conversion device whose output is proportional to some arbitrary fullscale value. In other words, the tranducer's absolute output value is of no particular concern but the ratio of the
output to the full-scale is of great importance. For example, the potentiometric displacement transducers of Figure 3 have this feature. When the wiper is at midscale, the output voltage is $\mathrm{V}_{\mathrm{O}}=\mathrm{V}_{\mathrm{F}} \times$ (Wiper Displacement) $=\mathrm{V}_{\mathrm{F}}$ $\times 0.5$. This enables the use of much less accurate and less expensive references. The important consideration for this reference is noise. The reference must be "glitch free"' because a voltage spike during a conversion cycle could cause conversion inaccuracies.


FIGURE 3. Ratiometric Converter with Separate Reference


FIGURE 2. ADC0808/ADC0809 Timing Diagram

Since highly accurate references aren't required it is possible to use the system power supply as a reference, as shown in Figure 4. If the power supply is to be used in this manner supply noise must be kept to a minimum to preserve conversion accuracy. If possible the supply should be well bypassed and separate reference and supply PC board traces, originating as close as possible to the power supply or regulator, should be used. This is illustrated in Figure 4.

External accessibility of both ends of the resistor ladder enables several variations on these basic connections, and are shown in Figures 5 and 6. The magnitude of the reference voltage, $\mathrm{V}_{\mathrm{REF}}=\operatorname{REF}(+)-\operatorname{REF}(-)$, can be varied from about $\sim 0.5 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{Cc}}$, but the center voltage must be maintained within $\pm 0.1 \mathrm{~V}$ of $\mathrm{V}_{\mathrm{CC}} / 2$. This constraint is due to the design of the transistor switch tree, which could malfunction if the offset from center scale becomes excessive. Variation of the reference voltage can sometimes eliminate the need for external gain blocks to scale the input voltage to a full-scale range of 5 V .


FIGURE 4. Ratiometric Converter with Power Supply Reference


FIGURE 5. Mid-Supply Centered Reference using LM336 2.5V Reference


FIGURE 6. Mid-Supply Centered Reference using Buffered Resistors

Figure 5 shows a center referencing technique, using two equal resistors to symmetrically offset an LM336 2.5 V reference, from both supplies. The offset from either supply is:

$$
V_{O F F}=\frac{V_{C C}-V_{\mathrm{REF}}}{2}=1.25 \mathrm{~V}
$$

These resistors should be chosen so that they limit current through the LM336 to a reasonable value, say 5 mA . The total resistor current is:

$$
I_{R}=I_{R E F}+I_{\text {LADDER }}+I_{\text {TRAN }}
$$

where $I_{\text {LADDER }}$ is the 256 ladder current, $I_{\text {TRAN }}$ is the current through all the transducers, and $\mathrm{I}_{\text {REF }}$ is the current through the reference. R1 and R2 should be well matched and track each other over temperature.
For odd values of reference voltage, the reference could be replaced by a resistor, but due to loading and temperature problems, these resistors should be buffered to the $\operatorname{REF}(+)$ and $\operatorname{REF}(-)$ inputs, Figure 6. The power supply must be well bypassed as supply glitches would otherwise be passed to the reference inputs. The reference voltage magnitude is:

$$
V_{\mathrm{REF}}=V_{\mathrm{DD}}\left(\frac{R 2}{2 R 1+R 2}\right) \quad R 3=R 1
$$

There are several op amps that can be used for buffering this ladder. Without adding another supply, an LM358 could be used if the $\operatorname{REF}(+)$ input is not to be set above 3.5 V . The LM10 can swing closer to the positive supply and can be used if a higher, $\mathrm{V}_{\mathrm{REF}(+)}$ voltage is needed.
As the $\operatorname{REF}(+)$ to $\operatorname{REF}(-)$ voltage decreases the incremental voltage step size decreases. At 5 V one LSB represents $\sim 20 \mathrm{mV}$, but at 1 V , one LSB represents $\sim 4 \mathrm{mV}$.

As the reference voltage decreases, system noise will become more significant so greater precaution should be enforced at lower voltages to compensate for system noise; i.e., adequate supply and reference bypassing, and physical as well as electrical isolation of the inputs.

### 2.2 Absolute Analog Inputs

The ADC0808/ADC0809 may have been designed to easily utilize ratiometric transducers, but this does not preclude the use of non-ratiometric inputs. A second type of input is the absolute input. This is one which is independent of the reference. This implies that its absolute numerical voltage value is very critical, and to accurately measure this voltage the accuracy of the reference voltage becomes equally critical. The previous designs can be modified to accommodate absolute input signals by using a more accurate reference. In Figure 4 the power supply reference could be replaced by an LM336-5.0 reference. R1 and R2 of Figure 6, and R1 and R3 of Figure 7 may have to be made more accurately equal.

In some small systems it is possible to use the precision reference as the power supply as shown in Figure 7. An unregulated supply voltage $>5 \mathrm{~V}$ is required, but the LM336-5.0 functions as both a regulator and reference. The dropping resistor R must be chosen so that, for the whole range of supply currents needed by the system, the LM336-5.0 will stay in regulation. As in Figure 4 separate supply and reference traces should be used to maintain a noiseless supply.
If the system requires more power, an op amp can be used as shown in Figure 8 to isolate the reference and boost the supply current capabilities. Here again, a single unregulated supply is required.

### 2.3 Differential Inputs

Differential measurements can be obtained by playing a little software trick. This simply involves sequentially converting two channels then subtracting the two results. For example, if the difference voltage between channel 1 and 2 is required, merely convert channel 1 and read the result. Then convert channel 2 , input the result, and subtract it
from the first result. (See Figure 9.) When using this procedure, both input signals must be stable throughout both conversion times or the end result will be incorrect. One way to get around this is to use two sample/holds which are sampled at the same time.


FIGURE 7. Precision Reference used as a Power Supply


FIGURE 8. Precision Reference Buffered for Power Supply


FIGURE 9. Software Controlled Differential Converter

A second method is to use two chips to convert a differential channel, Figure 10. Typically each channel 1 would be connected to opposite sides of the differential input. Both converters are started simultaneously. When both converters' EOC outputs go high the output of the AND gate will go high indicating that the data is ready to be read.

The circuit in Figure 10 can be slightly modified to provide increased data throughput by using two converters in a
parallel data acquisition scheme. Figure 11 shows this circuit in which all the input channels are connected in pairs through LF398 monolithic sample/holds. Under normal operation a sample/hold is accessed through an MM74C42 which will pulse an MM74C221, generating a sample pulse. After a sample/hold is done sampling the signal, the appropriate channel is started. If this process is alternated between two converters the sample rate can be doubled.

FIGURE 10. Dual Converter Differential Circuit



### 2.4 Analog Input Considerations

Analog inputs into the ADC0808/ADC0809 can handle any input signal that is maintained within the supply limits, but some careful consideration must be given to the out-
put impedance of the transducer or buffer. Using transducers with large source impedances can cause errors due to comparator input currents.


FIGURE 11. Parallel Data Acquisition with Sample/Holds

To understand the nature of these currents a short discussion of comparator operation is required. Figure 12 shows a simplified model of the comparator and multiplexer. This comparator alternately samples the input voltage and the ladder voltage. As it samples the input, $\mathrm{C}_{\mathrm{C}}$ and $\mathrm{C}_{\mathrm{P}}$ are charged up to the input voltage. It then samples the ladder and discharges the capacitor. The net charge difference is determined by a modified inverter chain and results in a 1 or 0 state at the output.

Eight samples are made per conversion, resulting in eight spikes of varying magnitude on the input.

If the source resistance is large, it adds to the RC time constant of the switched capacitor which will inhibit the input from settling properly, causing errors. As one might expect, the maximum source resistance allowable for accurate conversions is inversely proportional to clock frequency. This resistance should be $\leq 1 \mathrm{k} \Omega$ at 1.2 MHz and $\leq 2 \mathrm{k} \Omega$ at 640 kHz . If a potentiometer-type ratiometric transducer is used it should be $\leq 5 \mathrm{k} \Omega$ at 1.2 MHz and $\leq 10 \mathrm{k} \Omega$ at 640 kHz .

If large source impedances are unavoidable ( $\geq 2 \mathrm{k} \Omega$ at 640 kHz ), the transient errors can be reduced by placing a bypass capacitor $\geq 0.1 \mu \mathrm{~F}$ from the analog inputs to ground. This will reduce the spikes to a small average current which will cause some error as well, but this can be much less than the error otherwise incurred. The maximum voltage error for a potentiometer input with a bypass capacitor added is:

$$
V_{E R R} \approx\left[\frac{R_{P O T}}{5}\left(l_{\mathrm{I}}\right) \frac{C k}{640 \mathrm{kHz}}\right] V
$$

where $R_{\text {POT }}=$ total potentiometer resistance; $l_{I N}=$ maximum input current at $640 \mathrm{kHz}, 2 \mu \mathrm{~A}$; and $\mathrm{Ck}=$ clock frequency.

For standard buffer source impedance the maximum error is:

$$
V_{E R R}=\left[I_{I N} R_{S}\left(\frac{C k}{640 \mathrm{kHz}}\right)\right] V
$$

where $R_{S}=$ buffer source resistance; $l_{\mathbb{N}}=$ the maximum input current at $640 \mathrm{kHz}, 2 \mu \mathrm{~A}$; and $\mathrm{Ck}=$ clock frequency.

### 3.0 MICROPROCESSOR INTERFACING

The ADC0808/ADC0809 converters were designed to interface to most standard microprocessors with very little external logic, but there are a few general requirements which must be considered to ensure proper converter operation.

Most microprocessors are designed to be TTL compatible and, due to speed and drive requirements, incorporate many TTL circuits. The data outputs of the ADC0808/ ADC0809 are capable of driving one standard TTL load which is adequate for most small systems, but for larger systems extra buffering may be necessary. The EOC output is not quite as powerful as the data outputs, but normally it is not bussed like the data outputs.

The converter inputs are standard CMOS compatible inputs. When TTL outputs are connected to any of the digital inputs a pull-up resistor should be tied from the TTL output to $V_{C C}, \sim 5 \mathrm{k} \Omega$. This will ensure that the TTL will pull-up above 3.5 V .

Usually the converter clock will be derived from the microprocessor system clock. Some slower microprocessor clocks can be used directly, but at worst a few divider stages may be necessary to divide microprocessor clock frequencies above 1.2 MHz to a usable value.
The timing of the START and ALE pulses relative to channel selection and signal stability can be critical. The simplest approach to microprocessor interfaces usually ties START and ALE together. When these lines are strobed the address is strobed into the address register and the conversion is started. The propagation delay from ALE to the comparator input of the selected input signal is about $\sim 3.0 \mu \mathrm{~S}$ (input source resistance $\ll 1 \mathrm{k} \Omega$ ). If the start pulse is very short the comparator can sample the analog input before it is stable. When using a slow clock $\leq 500$ kHz the sample period of the comparator input is long enough to allow this delay to settle out.

If the ADC0808/ADC0809 clock is $>500 \mathrm{kHz}$, a delay between the START and ALE pulses is required. There are three basic methods to accomplish this. The first possibility is to design the microprocessor interface so that the START and ALE inputs are separately accessible. This is simple if some extra address decoding is available. Separate accessibility of the START and ALE pins allows the microprocessor, via software, to set the delay time between the START and ALE pulses.

If extra decoding is not available, then START and ALE could be tied together. To obtain the proper delay, the microprocessor would cause START/ALE to be strobed twice by executing the load and start instruction twice. The first time this instruction is executed, the new channel address is loaded and the conversion is started. The second execution of this instruction will reload the same channel address and restart the conversion. But since the multiplexer address register contents are unchanged the selected analog input will have already settled by the time the second instruction is issued. Actual implementations of these ideas are shown in following sections.


FIGURE 12. Analog Multiplexer and Comparator Input Model

A third possibility when ALE and START are tied together is to stretch the microprocessor derived ALE/START pulse by inserting a one-shot at these inputs and creating a positive pulse $>3 \mu \mathrm{~s}$. Since ALE loads the multiplexer register on the positive going edge of the pulse and START begins the conversion on the falling edge, the width of the pulse sets the ALE to START delay time.
Most microprocessor interfaces would be designed such that a START pulse is issued by a memory or I/O write instruction, although a memory or l/O read can be used. The ALE strobe on the other hand, requires a write by the CPU when $A, B$, and $C$ are connected to the data bus, and could use a read instruction if $A, B$, and $C$ are connected to the address bus, but the software could get confusing. The logic to derive the OE strobe must be connected to the microprocessor so that a memory or I/O read instruction will cause OE to be pulsed. A read is required since the ADC0808/ADC0809 data must be read.

### 3.1 Interfacing to the INS8080

The simplest interface would contain no address decoding, which may seem unreasonable; but if the system ports are I/O mapped, up to 8 of them can be connected to the CPU with no decoding. Each of the $8 \mathrm{I} / \mathrm{O}$ address lines would serve as a simple port enable line which would be gated with read and write strobes to select a particular port. This scheme is shown in Figure 13. A7 is the address line used and, whenever it is zero and an I/O read or write is low, the port is accessed. This implementation shows A, B, C connected to D0, D1, D2 causing the information on the data bus to select the channel, but A, B, and $C$ could be connected to the address bus, with a loss of only 3 ports. Both decoding schemes are tabulated in Figure 14. (Remember A, B, C inputs are only valid when selecting a channel to convert, and are not used to read data.)


FIGURE 13. Minimum INS8080/INS8224/INS8228 Interface


FIGURE 14a. Write Address Decoding for INS8080 Output Ports (A, B, C Connected to D0, D1, D2)

| A7 | A6 | A5 | A4 | A3 | A2 | A1 | A0 | Output Port <br> Description |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| 0 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | Channel 0 Port |
| 0 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | Channel 1 Port |
| 0 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | Channel 2 Port |
| 0 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | Channel 3 Port |
| 0 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | Channel 4 Port |
| 0 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | Channel 5 Port |
| 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | Channel 6 Port |
| 0 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | Channel 7 Port |
| 1 | 1 | 1 | 1 | 0 | $X$ | $X$ | $X$ | Spare Port |
| 1 | 1 | 1 | 0 | 1 | $X$ | $X$ | $X$ | Spare Port |
| 1 | 1 | 0 | 1 | 1 | $X$ | $X$ | $X$ | Spare Port |
| 1 | 0 | 1 | 1 | 1 | $X$ | $X$ | $X$ | Spare Port |

$X=$ don't care
FIGURE 14b. Modified Write Address Decoding for INS8080 Output Ports (A, B, C Connected to A0́, A1, A2)

Two LSTTL NOR gates are used to generate to the ADC0808/ADC0809 read/write strobes. When the INS8080 writes to the ADC0808/ADC0809 the ALE and START inputs are strobed, loading and starting the conversion. When the CPU reads the ADC0808/ADC0809 the OE input is taken high, and the data outputs are enabled.
Figure 13 implements a simple interrupt concept where EOC is tied directly to the INS8080 interrupt input. When the INS8228 is used and the INTA pin is tied high through a $1 \mathrm{k} \Omega$ resistor, the interrupt will cause a restart, RST, instruction to be executed, which will then cause a jump to a restart vector and execution of the interrupt routine. If a very simple multi-interrupt system is desired, a wire OR'ed configuration employing resettable latches as shown in Figure 13's inset can be used. In this simple design the MM74C74 is reset when the ADC0808/ADC0809 data is read. If more complicated interrupt structures are required, then an interrupt controller is usually the best solution.

The I/O port address structure for Figure 13's implementation is shown in Figure 14a. If the A, B, C inputs are tied to A0, A1, A2 inputs the port structure is as shown in Figure 14b. The later method makes each channel look like a separate port address whereas, if $A, B, C$ are tied to the data bus the ADC0808/ADC0809 looks like one start conversion port address, whose channel is selected by the 3 -bit status word written to it on the data bus.

Figure 15 shows a slightly more complex interface, where the address is partially decoded by a DM74LS139, dual 2-4 line decoder which creates the read and write strobes to operate the converter. This design interfaces to the processor in a polled type of interface. An MM80C97 TRISTATE ${ }^{\oplus}$ buffer is used to buffer the EOC line to the data bus, as well as provide the correct level tor the START, ALE, and OE pulses. The converter clock is a divided INS8080 system clock.


FIGURE 15. INS8080/INS8224/INS8228 Interface using Partial Decoding

Typically, the software to use Figure 15 would first select the desired channel by writing the channel address to the ALE port address, 01XXXCBA, where $X=$ don't care, and CBA is the channel address. Next the conversion is started by writing to the START address, 00XXXXXX. Now the processor must wait a few instruction cycles to allow EOC to fall. Once EOC falls, its status can be checked by reading the EOC line, address 01XXXXXX. When the EOC line is detected high again (a low on DO), the data can be read by accessing the OE port, address 00XXXXXX. As in the previous example the $A, B, C$ inputs can be tied to $D 0$, D1, D2 rather than A0, A1, A2, so that the information on

| ; START CONVERSION (A, B, C CONNECTED TO D0, D1, D2) |  |  |  |
| :---: | :---: | :---: | :---: |
| CHANN1 | EQU | 7 |  |
| START1 | EQU | 7FH |  |
| DATA | EQU | 7 FH |  |
| START: | LDA | CHANN1 | ; LOAD CHANNEL ADDRESS INTO ACE |
|  | OUT | START1 | ; STORE IT TO ADC0808/ADC0809 AND START |
|  | OUT | START1 | ; RESTART ADC0808/ADC0809 TO ACCOUNT FOR |
| ; |  |  | ; MULTIPLEXER DELAY |
|  | El |  | ; ENABLE INTERRUPTS IF NOT ALREADY |
|  | - | - | ; PROCESS PROGRAM |
| ; INTERRUPT HANDLER ROUTINE |  |  |  |
| INTRP: |  |  |  |
|  | IN | DATA | ; READ DATA AND RESET INTERRUPT |
|  | - | - | ; PROCESS DATA |
|  | El |  | ; ENABLE INTERRUPTS IF DESIRED |
|  | RET |  | ; RETURN TO MAIN PROGRAM |
|  | FIGURE 16a. Typical 8080 Resettable Interrupt I/O Routines |  |  |
| ; START CONVERSION (A, B, C CONNECTED TO AO, A2, A3) AND POLL EOC <br> ; (FIGURE 15) |  |  |  |
|  |  |  |  |
| SELECT | EQU | 40 H | ; SELECT CHANNEL 0 |
| START | EQU | OOH | ; START CONVERTER |
| EOCIN | EQU | 40 H | ; READ EOC |
| DATA | EQU | . 00 H | ; READ DATA |
| START: | OUT | SELECT | ; SELECT CHANNEL |
|  | OUT | START | ; START CONVERSION |
|  | NOP |  | ; INSERT INSTRUCTIONS TO WAIT 0-8 |
|  | NOP |  | ; CLOCK PERIODS OF ADC0808/ADC0809 CLOCK |
|  | NOP |  | ; FOR EOC TO DROP (8 NOPs MINIMUM) |
|  | NOP |  |  |
|  | NOP |  |  |
| ; READ AND TEST EOC |  |  |  |
| STATUS: |  |  |  |
|  | IN | EOCIN | ; INPUT EOC BIT |
|  | ANI | 01 H | ; MASK OUT OTHER BITS |
| , | JZ | READY | ; IF INPUT BIT IS ZERO JUMP READY |
|  | - | - | ; ELSE CONTINUE EXECUTING PROGRAM |
| ; OR |  |  |  |
| ; CONTINUOUS POLLING ROUTINE |  |  |  |
|  |  |  |  |
| STAT 2: | IN | EOCIN | ; INPUT EOC STATUS BIT |
|  | ANI | 01H | ; MASK OUT ALL BITS BUT DO |
|  | JNZ | STAT 2 | ; JUMP TO TRY AGAIN IF NOT READY |
| READY: | IN | DATA | ; IF READY INPUT DATA |
|  | - | - | ; CONTINUE EXECUTING PROGRAM |

the data bus selects the channel to be converted. Figure 15 can be connected in an interrupt mode by incorporating the interrupt flip-flop of Figure 13.

A few typical utility routines to operate the ADC0808/ ADC0809 application in Figure 13 are shown in Figure 16a. These routines assume that the resettable interrupt flipflop is used. Figure 16b illustrates some typical polled I/O routines for Figure 15. Notice that in Figure 16a the OUT START. 1 instruction is executed twice to allow the analog input signal to settle as discussed earlier.

The application in Figure 17 uses a 6-bit bus comparator and a few gates to decode a read and write strobe. Viewed from the CPU this interface looks like a bidirectional data port whose address is set by the logic levels on the $T_{n}$ inputs of the DM8131 comparator. When data is written to the ADC0808/ADC0809 the 3 least significant bits on the address bus define the channet to be converted. The rest of the bits are decoded to provide the START and ALE strobes. When the conversion is completed EOC sets the interrupt flip-flop, and when the data is read the interrupt is reset.
Both the decoder and the bus comparator methods of address decoding have their own advantages. Bus comparators will more completely decode addresses but are capable of only a limited number of port strobes. Decoders, on the other hand, provide less decoding but more port strobes. There is a trade off for minimum parts systems as far as which route to go, and it will depend on the CPU and type of system.

### 3.2 Interfacing to the 6800

The ADC0808/ADC0809 easily interface to more than one microprocessor. The 6800 can also be used to control the converter. The 6800 has no separate I/O address space so all I/O transfers must be memory mapped. In general more address decoding logic is required to ensure that the I/O ports don't overlap existing memory. For small systems a partial address decoding scheme is shown in Figure 18. Generally, if several ports are desired, a small block of
memory would be set aside, as is accomplished by the DM8131. Figure 18 also illustrates a typical 6800 interrupt scheme using a flip-flop and open collector transistor. The interrupt is reset when the data is read. If more ports are needed, a decoder could be added as shown in Figure 19. Figure 19 also illustrates a polled I/O mode using TRISTATE ${ }^{\circledR}$ buffer to gate EOC onto the data bus. As with the INS8080 the A, B, C inputs of the ADC0808/ADC0809 can be connected to the address bus or the data bus.

The 6800 differs from the INS8080 in that the 6800 has a single read/write ( $\mathrm{R} \overline{\mathrm{W}}$ ) strobe and a valid memory address (VMA), whereas the INS8080 has separate read and write strobes ( $\overline{/ / O R}$ and $I / \overline{O W})$. Normally, to obtain a read pulse, VMA, R $\bar{W}$ and $\phi_{2}$ are gated together and, for a write, $\mathrm{R} \bar{W}$ is inverted. $\phi_{2}$ is the 6800 phase 2 system clock. Also notice that the 6800 INT interrupt input is active low. This enables a standard wired-OR open collector design to be implemented.
Figure 20 illustrates some typical 6800 software utility routines for either polled or interrupt interfaces. Again notice double start instructions.

### 3.3 Z80 Interface

Interfacing the Z80 to the ADC0808 is much the same as interfacing to an INS8080/INS8224/INS8228 CPU group. CPU instruction timing is very similar, except the read/write control signals are slightly different. Instead of the $\overline{/ O W}$ write strobe there is the $\overline{\mathrm{OREQ}}$ and $\overline{\mathrm{WR}}$ and instead of $\overline{I / O R}, \overline{I O R E Q}$ and $\overline{R D}$ are supplied.


FIGURE 17. Interrupt-Type INS8080/INS8224/INS8228 Interface using 6-Bit Bus Comparator



FIGURE 18. Typical 6800 Interface with Partial Address Decoding


FIGURE 19. Fully Decoded 6800 Interface Address

```
*
*UTILITY ROUTINES FOR ADC0808/ADC0809 INTERFACE
*
* LOAD AND START CONVERSION (FIGURE 18)
*
    STATUS EQU $D800
    DATA EQU
$D800
*
*
*
\begin{tabular}{lll} 
START & STA & STATUS \\
& STA & STATUS \\
& LDX & \#VECTOR \\
& STX & \$FFF8 \\
& -- & \\
& -- & \\
& CLI & \\
& WAI &
\end{tabular}
DATA
CLI
- -
RTI
*START AND TEST CONVERSION POLLED MODE (FIGURE 19)
*
```

DATA2 CHANN2 EOCIN START 2

EQU
EQU EQU LDAA STAA NOP STAA NOP

-     - 

LDAA ANDA BEQ
\$F800
02
\$F900
CHANN 2
STATUS

STATUS

EOCIN
01
READY

START ADDRESS FOR CHANNEL 0 CONVERTER DATA ADDRESS

SELECT CHANNEL 0 AND START DO AGAIN TO LET INPUTS SETTLE LOAD INTERRUPT VECTOR ADDRESS STORE IT EXECUTE MISC PROGRAM

ENABLE INTERRUPT IF NOT ALREADY EXECUTE MISC PROGRAM WAIT FOR INTERRUPT

LOAD DATA RESET INTERRUPT ENABLE INTERRUPTS (OPTION) EXECUTE PROGRAM RETURN TO MAIN PROGRAM

CONVERTER DATA ADDRESS CHANNEL 2 ADDRESS EOC INPUT PORT LOAD A ACCUMULATOR LOAD ADDRESS AND START WAIT RESTART TO LET MUX SETTLE 8 NOPS TO WAIT FOR EOC TO GO LOW
LOAD EOC STATUS BIT MASK BITS 1-7 IF A $=0$ THEN CONVERTER DONE

EXECUTE MISC PROGRAM

LOAD EOC STATUS MASK MSBs
IT ACC $=0$ NOT READY, LOOP
ELSE READ DATA
CONTINUE PROGRAM

Figure 21 shows a very simple $Z 80$ interface, which is similar to the INS8080 interface of Figure 13, except that the interrupt flip-flop design is closer to the 6800 designs. This is because the Z80 INT is active low as is the 6800, but the INS8080 INT is active high.

Figure 22 shows a fully decoded bus comparator design where the DM8131 decodes 5 address bits and the IOREQ I/O request strobe. Two NOR gates gate the $\overline{R D}$ and $\overline{W R}$ strobes for ALE, START and OE inputs.

### 4.0 CONCLUSION

Both the ADC0808 and the ADC0809 can be easily used in microprocessor controlled environments. Many sophisticated medium throughput applications can be handled with a minimum of extra hardware, but additional hardware can increase flexibility and simplify software. Putting both the multiplexer and $A / D$ on the same chip frees the designer from matching multiplexers and A/Ds to implement a 7 or 8 -bit accurate system. Design time and overall system cost can be reduced by using these low cost converters.


FIGURE 21. Simple Z80 Interface


## Electrostatic Discharge Prevention - Input Protection Circuits and Handling Guide for CMOS Devices

## Introduction

During the past few years, there have been significant increase in the usage of low-power CMOS devices in system designs. This has resulted in more stringent attention to handling techniques of these devices, due to their static sensitivity, than ever before.
All CMOS devices, which are composed of complementary pairs of n - and p -channel MOSFET's, are susceptible to damage by the discharge of electrostatic energy between any two pins. This sensitivity to static charge is due to the fact that gate input capacitance ( 5 picafarads typical) in parallel with an extremely high input resistance ( $10^{12}$ ohms typical) lends itself to a high input impedance and hence readily builds up the electrostatic charges, unless proper precautionary measures are taken. This voltage build-up on the gate can easily breakdown the thin ( $1000 \AA$ ) gate oxide insulator beneath the gate metal. Local defects such as pinholes or lattice defects of gate oxide can substantially reduce the dielectric strength from a breakdown field of $8.10 \times 10^{6} \mathrm{~V} / \mathrm{cm}$ to $3-4 \times 10^{6} \mathrm{~V} / \mathrm{cm}$. This then becomes the limiting factor on how much voltage can be applied safely to the gates of CMOS devices.
When a higher voltage, resulting from a static discharge, is applied to the device, permanent damage like a short to substrate, $\mathrm{V}_{\mathrm{DD}}$ pin, $\mathrm{V}_{\mathrm{SS}}$ pin, or output can occur. Now static electricity is always present in any manufacturing environment. It is generated whenever two different materials are rubbed together. A person walking across a production floor can generate a charge of thousands of volts. A person working at a bench, sliding around on a stool or rubbing his arms on the work bench can develop a high static potential. Table 1 shows the results of work done by Speakman ${ }^{1}$ on various static potentials developed in a common environment. The ambient relative humidity, of course, has a great effect on the amount of static charge developed, as moisture tends to provide a leakage path to ground and helps reduce the static charge accumulation.

Table 1. Various Voltages Generated in $15 \% \cdot 30 \%$ Relative Humidity (after Speakman ${ }^{1}$ )

| Condition | Most Common <br> Reading <br> (Volts) | Highest <br> Reading <br> (Volts) |
| :--- | :---: | :---: |
| Person walking across <br> carpet | 12,000 | 39,000 |
| Person walking across <br> vinyl floor | 4,000 | 13,000 |
| Person working at bench <br> 16-lead DIPs in plastic <br> box <br> 16-lead DIPs in plastic <br> shipping tube | 500 | 3,000 |
|  | 3,500 | 12,000 |
|  | 500 | 3,000 |

National Semiconductor Application Note 248
Vivek Kulkarni
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## Standard Input Protection Networks

In order to protect the gate oxide against moderate levels of electrostatic discharge, protective networks are provided on all National CMOS devices, as described below.

Figure 1 shows the standard protection circuit used on all A, B, and 74C series CMOS devices. The series resistance of 200 ohms using a $\mathrm{P}^{+}$diffusion helps limit the current when the input is subjected to a high-voltage zap. Associated with this resistance is a distributed diode network to $V_{D D}$ which protects against positive transients. An additional diode to $V_{S S}$ helps to shunt negative surges by forward conduction. Development work is currently being done at National on various other input protection schemes.


Figure 1. Standard Input Protection Network

## Other Protective Networks

Figure 2 shows the modified protective network for CD4049/4050 buffer. The input diode to $V_{D D}$ is deleted here so that level shifting can be achieved where inputs are higher than $V_{D D}$.


Figure 2. Protective Network for CD4049/50 and MM74C901/2

Figure 3 shows a transmission gate with the intrinsic diode protection. No additional series resistors are used so the on resistance of the transmission gate is not affected.

All CMOS circuits from National's CD4000 Series and 74C Series meet MIL-STD-38510 zap test requirements of 400 volts from a 100 pF charging capacitor and $1.5 \mathrm{k} \Omega$ series resistance. This human body simulated model of


Figure 3. Transmission Gate with Intrinsic Diodes to Protect Against Static Discharge
100 pF capacitance in series with $1.5 \mathrm{k} \Omega$ series resistance was proposed by Lenzlinger ${ }^{2}$ and has been widely accepted by the industry. The set-up used to perform the zap test is shown in Figure 4.
$V_{\text {ZAP }}$ is applied to DUT in the following modes by charging the 100 pF capacitor to $\mathrm{V}_{\text {ZAP }}$ with the switch $\mathrm{S}_{1}$ in position 1 and then switching to position 2, thus discharging the charge through $1.5 \mathrm{k} \Omega$ series resistance into the device under test. Table 2 shows the various modes used for testing.

Table 2. Modes of High-Voltage Test

| Mode | + Terminal | - Terminal |
| :---: | :---: | :---: |
| 1 | Input | $V_{S S}$ |
| 2 | $V_{D D}$ | Input |
| 3 | Input | Associated Output |
| 4 | Associated Output | Input |

Pre- and post-zap performance is monitored on the input leakage parameter at $\mathrm{V}_{\mathrm{DD}}=18$ Volts. It has been found that all National's CMOS devices of CD4000 and 74C families can withstand 400 volts zap testing with above mentioned conditions and still be under the pre- and post-zap input leakage conditions of $\pm 10 \mathrm{nA}$.

## Handling Guide for CMOS Devices

From Table 1, it is apparent that extremely high static voltages generated in a manufacturing environment can destroy even the optimally protected devices, by reaching their threshold failure energy levels. For preventing such catastrophies, simple precautions taken could save thousands of dollars for both the manufacturer and the user.

In handling unmounted chips, care should be taken to avoid differences in voltage potential between pins. Conductive carriers such as conductive foams or conductive rails should be used in transporting devices. The following simple precautions should also be observed.

1. Soldering-iron tips, metal parts of fixtures and tools, and handling facilities should be grounded.
2. Devices should not be inserted into or removed from circuits with the power on because transient voltages may cause permanent damage.
3. Table tops should be covered with grounded conductive tops. Also test areas should have conductive floor mats.


Figure 4. Equivalent RC Network to Simulate Human Body Static Discharge (After Lenzlinger ${ }^{2}$ )

Above all, there should be static awareness amongst all personnel involved who handle CMOS devices or the sub-assembly boards. Automated feed mechanisms for testing of devices, for example, must be insulated from the device under test at the point where devices are connected to the test set. This is necessary as the transport path of devices can generate very high levels of static electricity due to continuous sliding of devices. Proper grounding of equipment or presence of ionizedair blowers can eliminate all these problems.

At National all CMOS devices are handled using all the precautions described above. The devices are also transported in anti-static rails or conductive foams. Antistatic, by definition ${ }^{3}$ means a container which resists generation of triboelectric charge (frictionally generated) as the device is inserted into, removed from, or allowed to slide around in it. It must be emphasized here that packaging problems will not be solved merely by using anti-static rails or containers as they do not necessarily shield devices from external static fields, such as those generated by a charged person. Commercially available static shielding bags, such as 3M company's low resistivity ( $\leqslant 10^{4}$ ohms/sq.) metallic coated polyester bags, will help prevent damages due to external stray fields. These bags work on the well-known Faraday cage principle. Other commercially available materials are Legge company's conductive wrist straps, conductive floor coating, and various other grounding straps which help prevent against the electrostatic damage by providing conductive paths for the generated charge and equipotential surfaces.

It can be concluded that electrostatic discharge prevention is achievable with simple awareness and careful handling of CMOS devices. This will mean wide and useful applications of CMOS in system designs.

## Footnotes

1. T.S. Speakman, "A Model for the Failure of Bipolar Silicon Integrated Circuits Subjected to ESD," 12th Annual Proc. of Reliability Physics, 1974.
2. M. Lenzlinger, "Gate Protection of MIS Devices," IEEE Transac. on Electron Devices, ED-18, No. 4, April 1971.
3. J.R. Huntsman, D.M. Yenni, G. Mueller, "Fundamental Requirements for Static Protective Containers." Presented at 1980 Nepcon/West Conference, Application Note - 3M Static Control Systems.

# Simplified Multi-Digit LED Display Design Using MM74C911/MM74C912 MM74C917 Display Controllers 

National Semiconductor Application Note 257
Larry Wakeman
January 1981


## II. Functional Description - MM74C911

The functional block diagram for the MM74C911 is shown in Figure 1. The eight data inputs are buffered and bussed to the four dual-port latches. To write data into a particular latch, K1 and K2 address inputs are decoded and the proper latch is enabled when $\overline{C E}$ and $\overline{W E}$ are taken low.

The latch outputs are controlled by the multiplexer (MUX) logic. All four latch data outputs are commonly bussed, and are sequentially read by the MUX logic. The bussed 8 -segment outputs are then buffered by bipolar segment driver transistors, which are enabled when $\overline{\text { SOE }}$ is low, and are tri-stated when Segment Output Enable ( $\overline{\mathrm{SOE}}$ ) is held high. This allows easy display blanking without loss of data.

The multiplexer logic controls all of the timing for the MM74C911 and also generates the digit output strobes. The timing diagram is shown in Figure 2.


Figure 1. MM74C911 Block Diagram


Figure 2. Mux Timing for MM74C911
By raising the Digit In-Out ( $\overline{\mathrm{DIO}}$ ) input high, the internal oscillator is disabled and the digit outputs become inputs which control reading of the 4 -digit latches. This allows the MM74C911 to be slaved to other multiplex timing signals. If both $\overline{\mathrm{SOE}}$ and $\overline{\mathrm{DIO}}$ are held high, both the display and oscillator are disabled causing the MM74C911 to be in a low-power mode where it typically draws less than $1 \mu \mathrm{~A}$. Figure 3 shows the truth table for these control inputs.

| DIO/OSE | SOE | MODE |
| :---: | :---: | :--- |
| 0 | 0 | NORMAL DISPLAY MODE |
| 0 | 1 | DISPLAY BLANKED |
| 1 | 0 | WILL DISPLAY ONE DIGIT* |
| 1 | 1 | LOW POWER MODE |

Figure 3. Operating Modes for the MM74C911/ MM74C912/MM74C917 (*The 74C911 Digit Outputs become inputs.)

## III. Functional Description MM74C912/MM74C917

The functional block diagram for the MM74C912 and MM74C917 is shown in Figure 4. These devices are very
similar to the MM74C911. There are only five data inputs on the MM74C912 and MM74C917 which are buffered, then bussed to six 5-bit dual-port latches. The address present on K1, K2, and K3 will dictate which of the six latches will be loaded when both $\overline{C E}$ and $\overline{W E}$ are low. The outputs of all of the latches are commonly bussed and fed into a decoder ROM which converts BCD (MM74C912) or hexidecimal (MM74C917) code to seven segment. The fifth bit is the decimal point, which bypasses the ROM. The 8 -segment bits are then buffered by eight NPN-segment drivers. Like the MM74C911, these outputs are tri-stateable and will blank the display when $\overline{\mathrm{SOE}}$ is held high.

All of the multiplexing is controlled by an internal oscillator and control logic. The logic sequentially reads each latch and activates the digit outputs. The oscillator can be disabled by raising the Oscillator Enable (OSE) input high, but the digit outputs do not become inputs and thus the MM74C912, and MM74C917 can not be slaved. However, by raising both $\overline{\mathrm{SOE}}$ and $\overline{\mathrm{OSE}}$ high, these parts can be put into a low-power mode similar to the MM74C911. Figure 3 shows the controller operating modes.

The MM74C912 and the MM74C917 are identical except for the last seven ROM locations. The ROM outputs are shown in Figure 5 for both parts.

## IV. Display Interface Design

## A. Common Cathode LED's

Since the MM74C911/MM74C912/MM74C917 contain all the multiplex circuitry necessary to operate a 4 - or 6 -digit display, all the designer must do is choose apropriate segment resistors and digit drivers to properly illuminate the LEDs. A typical LED connection is shown in Figure 6. Based on the selected display, a certain segment current will be required. This current will determine the value of the segment resistor and the type of digit driver necessary. The design for the MM74C911 is


Figure 4. MM74C912 and MM74C917 Display Controller


Figure 5. MM74C912/MM74C917 Character Fonts

(a)

(b)

Figure 6. Typical LED Connections for (a) MM74C912/MM74C917 (b) MM74C911
nearly the same as for the MM74C912/MM74C917 except that due to multiplexing the 6 -digit controllers must be designed to a higher peak current value.

As an example, suppose the the NSN781 (2-digit, 0.7" common catholde LED display) has been selected. These displays require an average current of 8 mA per segment for good illumination. The MM74C911 multiplexes four digits; thus, any one digit is on $1 / 4$ of the time. Each digit must have a peak current four times its average current to achieve the same brightness. The MM74C911 must supply about 32 mA per segment, and the MM74C912/MM74C917 would have to supply a current six times the average current or about 48 mA .
The maximum digit driver current is the maximum number of "on" segments multiplied by the segment current. For the MM74C911 design, the digit current is $\sim 260 \mathrm{~mA}$, and is $\sim 380 \mathrm{~mA}$ for the MM74C912/MM74C917. Using this digit current value, the digit driver can be selected. Figure 7 shows possible digit driver ICs, but discrete transistors or Darlingtons may also be used, and may be desireable in some higher current applications. It is also important to keep in mind that the output voltage of the driver at the designed current, as this voltage can affect the display controllers current drive. For most designs, an output voltage of $\angle 2 \mathrm{~V}$ is reasonable.

Once the digit driver has been chosen and the output voltage at the desired current is known, the segment resistor, $\mathrm{R}_{\text {SEG }}$ can be calculated using:

$$
R_{S E G}=\frac{V_{S E G}-V_{L E D}-V_{D O}}{I_{S E G}}
$$

where $\mathrm{V}_{\text {LED }}$ is the voltage across the LED, $1.8 \mathrm{~V} ; \mathrm{V}_{\mathrm{DO}}$ is the digit driver output voltage at the chosen current; $I_{\text {SEG }}$ is the peak segment current; and $V_{\text {SEG }}$ is the MM74C911 or MM74C912 segment driver output voltage at the peak segment current, which can be determined from the curves in Figure 8.

In most cases, $\mathrm{R}_{\text {SEG }}$ can be more quickly determined from Figure 9 which plots $\mathrm{R}_{\mathrm{SEG}}$ vs. average segment current. These curves are plotted for various digit driver output voltages using current values from Figure 8. Thus, for the above example, if a DS75492 driver I.C. is used with the MM74C911 to interface to the NSB781 LEDs $\mathrm{R}_{\text {SEG }}=38 \Omega$ assuming the drivers output voltage is 1.0 V . Note that Figure 7 tabulates minimum output drive where the above $V_{D O}$ is an approximation of the DS75492s typical $\mathrm{V}_{\text {DO }}$ at 260 mA .

| Part Number | Driver Type | Number of Drivers | Minimum Output Drive |
| :---: | :---: | :---: | :---: |
| DS75492 | Darlington Driver | 6 | 250 mA @1.5V |
| DS75494 | Multiple Transistor Driver | 6 | $150 \mathrm{mA@} 0.35 \mathrm{~V}$ |
| DS8646 | Transistor Driver | 6 | $84 \mathrm{mA@} 0.55 \mathrm{~V}$ |
| DS8658 | Transistor Driver | 4 | $84 \mathrm{~mA} @ 0.55 \mathrm{~V}$ |
| DS8870 | Darlington Driver | 6 | $350 \mathrm{mA@1.4V}$ |
| DS8871/2 | Transistor Driver | 8/9 | $40 \mathrm{mA@0.5V}$ |
| DS8877 | Transistor Driver | 6 | $35 \mathrm{mA@0.5V}$ |
| DS8920 | Transistor Driver | 9 | $40 \mathrm{mA@0.5V}$ |
| DS8963 | Darlington Driver | 8 | $500 \mathrm{mA@} 1.5 \mathrm{~V}$ |
| DS8978 | Transistor Driver | 9 | $100 \mathrm{~mA} @ 0.7 \mathrm{~V}$ |
| DS8692 | Transistor Driver | 8 | 350 mA @1.0V |

Figure 7. Typical LED Digit Drivers and Their Characteristics


Figure 8. Typical Segment Driver Current vs. Output Voltage for (a) MM74C911 (b) MM74C912/MM74C917
(a)


AVERAGE/PEAK SEGMENT CURRENT (mA)
(b)


AVERAGE/PEAK SEGMENT CURRENT (mA)

Figure 9. Average LED Segment Current vs. Segment Resistor for (a) MM74C911 (b) MM74C912/MM74C917

Figures 10 and 11 tabulate some typical segment resistor values for various National LED displays. (See Optoelectronics Databook for detailed specifications.) This table was compiled for a well lit room, but variation in ambient lighting may require some slight modification in the typical segment resistor values.

If a transistor digit driver is being used, it is sometimes desireable to use a base current limiting resistor between the controller's output and the transistor's base. This will help limit the power dissipation of the display controller in critical situations. The digit resistor, $\mathrm{R}_{\text {DIG }}$ can be calculated using:

$$
R_{D I G}=\frac{V_{D I G}-V_{D I}}{I_{D I}}
$$

where $\mathrm{V}_{D 1}$ is the digit driver input voltage, 0.7 V for a transistor, $I_{D I}$ is the desired digit driver current and $V_{D I G}$ is the controller's digit output voltage for the chosen current which can be found from Figure 12.

When the MM74C911 is to be used as a "master" to drive another MM74C911 or other logic, the digit outputs must have a high output voltage of 3.0 V to driver another MM74C911 or 3.5 V to drive standard CMOS logic. The digit resistor should be $>300 \Omega$ for $\mathrm{V}_{\mathrm{OH}} \geqslant 3.0 \mathrm{~V}$ and $R_{\text {DIG }}>350$ for $V_{O H} \geqslant 3.5 \mathrm{~V}$.
A final design consideration is power dissipation. When designing a low-power system where the total current is to be minimized, the total system power consumption is simply:

$$
\mathrm{P}_{\mathrm{T}} \cong \mathrm{~V}_{\mathrm{CC}}\left[\mathrm{l}_{\mathrm{DO}}+\mathrm{I}_{\mathrm{DI}}\right]
$$

| DISPLAY |  |  | DRIVER | TYPICAL RANGE OF SEGMENT RESISTORS |
| :---: | :---: | :---: | :---: | :---: |
| PART NO. | HEIGHT (IN.) | NO. OF DIGITS |  |  |
| NSA1298 | 0.110 | 9 | DS75492 | $\begin{aligned} & 300-1000 \Omega \\ & 300-2000 \Omega^{*} \end{aligned}$ |
| NSA1558 | 0.140 | 8 | DS75492 | $\begin{gathered} 200-800 \Omega \\ 200-1800 \Omega^{*} \end{gathered}$ |
| NSN381 | 0.3 | 2 | $\begin{aligned} & \text { DS75492 } \\ & \text { 2N3904 } \end{aligned}$ | 15-80 $\Omega$ |
| NSB3881 | 0.5 | 4 | $\begin{array}{r} \text { DS75492 } \\ \text { 2N3904 } \end{array}$ | 15-80 $\Omega$ |
| NSN581 | 0.5 | 2 | $\begin{aligned} & \text { DS75492 } \\ & \text { 2N3904 } \end{aligned}$ | 10-60 $\Omega$ |
| NSB5881 | 0.5 | 4 | $\begin{aligned} & \text { DS75492 } \\ & \text { 2N3904 } \end{aligned}$ | 10-60 $\Omega$ |
| NSN781 | 0.7 | 2 | $\begin{aligned} & \text { DS75492 } \\ & \text { 2N3904 } \end{aligned}$ | 10-50 $\Omega$ |
| NSB7881 | 0.7 | 4 | $\begin{aligned} & \text { DS75492 } \\ & \text { 2N3904 } \end{aligned}$ | 10-50 $\Omega$ |

Figure 10. MM74C911 Segment Resistor Values for Various Displays ( $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ ) (*Using Red LED Filter over Display)

| DISPLAY |  |  | $\begin{aligned} & \text { DRIVER } \\ & \left(R_{D}=0\right) \end{aligned}$ | TYPICAL RANGE OF SEGMENT RESISTORS |
| :---: | :---: | :---: | :---: | :---: |
| PART NO. | HEIGHT (IN.) | NO. OF DIGITS |  |  |
| NSA1298 | 0.110 | 9 | DS75494 | $\begin{gathered} 200-800 \Omega \\ 300-1500 \Omega^{*} \end{gathered}$ |
| NSA1558 | 0.140 | 8 | DS75494 | $\begin{gathered} 150-700 \Omega \\ 150-1000 \Omega^{*} \end{gathered}$ |
| NSN381 | 0.3 | 2 | DS75492 | 5-50 $\Omega$ |
| NSB581 | 0.5 | 2 | DS75492 | 5-50 $\Omega$ |
| NS5931 | 0.5 | 6 | $\begin{aligned} & \text { DS75492 } \\ & \text { 2N3904 } \end{aligned}$ | 5-40 $\Omega$ |
| NSN781 | 0.7 | 2 | $\begin{aligned} & \text { DS75492 } \\ & \text { 2N3904 } \end{aligned}$ | 5-30 $\Omega$ |

Figure 11. MM74C912/MM74C917 Segment Resistor for Average Intensity for Various Displays (*Using Red LED Filter Over Dlsplay)



Figure 12. Typical Digit Driver Current vs. Output Voltage for (a) MM74C911 (b) MM74C912/MM74C917
where $I_{D O}$ is the maximum digit driver output current, $V_{C C}$ is the power supply voltage, and $I_{D I}$ is the digit driver input current.
When a circuit design employs large segment currents, the maximum dissipation should be calculated to ensure that the power consumption of the controller or digit driver is within the maximum limits. The display controller power dissipation is:

$$
P_{\mathrm{C}}=\mathrm{S}\left(I_{\mathrm{SEG}}\right)\left(\mathrm{V}_{\mathrm{CC}}-\mathrm{V}_{\mathrm{SEG}}\right)
$$

where $I_{\text {SEG }}$ and $V_{\text {SEG }}$ are the peak segment current and segment voltage, as previously determined; and $S$ is the maximum number of segments lit per digit. The maximum package dissipation for the controllers vs. temperature is shown in Figure 13.
To gain an understanding of how segment current affects the controllers power dissipation, Figure 14 plots average and peak LED segment current vs. package dissipation for both the MM74C911 and the MM74C912/MM74C917. These typical curves are plotted using the typical segment driver output currents and voltages from Figure 8.

As the digit driver output voltage $V_{D O}$ becomes larger, the driver dissipates more power, thus the designer should also ensure that the driver's dissipation is not exceeded. Generally, the standard digit driver IC will dissipate around $1 / 2$ watt. (See specific data sheets.) Driver power dissipation can be calculated by:

$$
P_{D}=\left(V_{D O}\right)\left(I_{D I G}\right)
$$

where $V_{D O}$ and $I_{D I G}$ are the digit driver output voltage and current. In a standard digit driver, one output will be active all the time, but if discrete transistors are used, each transistor is turned on $25 \%$ of the time. The average power dissipation for each discrete transistor digit driver is $1 / 4$ of the above equation.

## B. Common Anode LED Display

Although connecting the MM74C911/MM74C912/MM74C917 to common anode displays is somewhat more difficult than to common cathode displays, it can be done. These controllers still provide all the necessary timing signals, but some extra buffering must be added to ensure the correct logic levels and drive capability.


Figure 13. MM74C911/MM74C912MM74C917 Maximum Power Dissipation for (a) Plastic " $N$ " Package (b) Ceramic " J " Package ( Note $\mathrm{T}_{\mathrm{J}_{(\text {MAX }}}=125^{\circ} \mathrm{C}$ Maximum Junction Temperature)


Figure 14. Typical Power Dissipation vs. Segment Current for (a) MM74C911 (b) MM74C912/MM74C917

To drive common anode displays, the display controller's segment outputs must be inverted and the digit outputs must be current buffered. Figure 15 shows a simple circuit to interface to most common anode displays. An 8-digit calculator digit driver IC, DS8871, is used to drive the display segments. Segment resistors on the controller's segment outputs are not necessary but may be necessary on the outputs of the DS8871 driver.
For higher current displays, the choice of digit driver transistor is important as the digit current will depend on how high the digit driver output of the display controller can pull up due to the emitter follower configuration. For good display brightness, a high gain medium power transistor should be used.

## C. Vacuum Florescent (VF) Displays

The MM74C911/MM74C912/MM74C917 are not directly capable of driving VF displays, but serve as a major functional block to ease driving 4- or 6-digit displays. The controllers provide the multiplex timing for this display, but the segment and digit outputs must be level shifted, and a filament voltage must be applied.

In Figure 16, a DS8654 or similar device is used to translate the segment and digit voltages to 30 V to drive the segment plates and digit grids. The AC filament voltage is derived from a separate low-voltage transformer which is biased by a zener. Since there is no pull-down in the DS8654, pull-down resistors must be added. The exact anode and cathode voltages and the bias zener will depend on the display used, but the basic circuit is the same.


Figure 15. MM74C911 to Common Anode LED Interiace Using 9 Digit Driver


Figure 16. MM74C912/MM74C917 to Vacuum Fluorescent Display Interface

## V．MM74C911 Display Applications

Of the three CMOS display controllers，the MM74C911 is the simplest，but also the most versatile．Since the char－ acter font is not predetermined，many non－numerical characters can be displayed using standard 8－segment displays．In many cases，it may be desireable to enable a small microprocessor to display prompt messages where the use of more complicated alpha－numeric dis－ plays is not justified．For these cases，the MM74C911 is ideal，because any combination of segments can be controlled．Figure 17 shows many of the possible letters and numbers that can be displayed along with their binary and hexidecimal values on 8－segment displays．
There is no reason to restrict the MM74C911 to alpha－numeric displays，as the controller allows direct control of individual LEDs．The MM74C911 can be con－ nected to a mixture of numerical and discrete LEDs as typified by Figure 18．Thus status and numerical data can be simultaneously controlled．
Taking this one step further，all the LEDs could be discrete as shown in Figure 19．This type of arrangement is multipurpose．The LEDs could be configured as a $4 \times 8$ matrix or possible two－bar graphs of 16 LEDs，Figure 20， or maybe some sort of binary data display．There are many variations possible．

## VI．Slaving The MM74C911

As mentioned，the MM74C911 has the unique feature of being able to be slaved to external multiplex logic or a ＂master＂MM74C911．This feature is useful when the controller is to be synchronized with a master．Figure 21 shows a typical application where two MM74C911s are used to drive a 16 －segment alpha－numeric display．In order to drive this display，synchronization is required to ensure that both controllers are outputting the same digit information at the same time．

A more subtle advantage to slaving MM74C911s occurs when trying to use multi－controllers to drive more digits． This case，illustrated in Figure 22，allows fewer，more powerful digit drivers to be used．This can be advanta－ geous when using smaller displays that require little power to begin with．

## VII．MM74C912／MM74C917 Display Applications

Both the MM74C911／MM74C912 have predetermined character fonts and this limits their versatility，but greatly simplifies their application in hex and decimal display application．Still，there are a few small＂tricks＂ that can be used to stretch the controller＇s capabilities．

In many applications，the decimal point segment is not needed，particularly when the MM74C917 is used：Gene－ rally，this part is used to display hexidecimal address and data information where decimal points are rarely needed．These segments could be used for status infor－ mation．Figure 23 shows a typical implementation．The status LEDs could indicate power，run and halt status information of a host $\mu \mathrm{P}$ or could indicate the type of instruction being executed．Although the MM74C912 applications would tend to use the decimal point more often，it is equally capable of implementing Figure 23.

Another possibility，if all six digits are not required，is to use the unused digits for status indicators．A possible example using the MM74C917 is shown in Figure 24， and another possible implementation for the MM74C912 is shown in Figure 25．In both of these applications，four bits of data is loaded into digits 1 and／or 2．Depending on the data loaded，various combinations of discrete LEDs would be lit．The tables included in these figures illustrate numerical combinations and their results．

| CHARACTER | HEX CODE FOR 74C911 | DISPLAY | CHARACTER | HEX CODE FOR 74C911 | DISPLAY |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | FC | $\square$ | $J$ | 78 | － |
| 1 | 60 | 1 | L | 1 C | $L$ |
| 2 | DA | 5 | N 0 | 2A | $\stackrel{17}{\square}$ |
| 3 4 | F2 66 | 7 | 0 | F 3 ［ | $\square$ |
| 5 | ${ }_{86} 6$ | 5 | P | CE | 品 |
| 6 | BE | E | R | OA | r |
| 7 | EO | 7 | S | B6 | 5 |
| 8 | FF | 日 | T | 8 C | E |
| 9 | F6 | 9 | U | 7 C | LI |
|  |  |  | U | 38 | 殅 |
| A | EE | 17 <br> $\square$ | Y | 76 48 | 4 <br> $H$ <br> 1 |
| C | 9 C | E |  |  |  |
| D | 7 A | － | （Blank） | 00 |  |
| E | 9 E | E | ． | 01. | $\cdot$ |
| G | ${ }_{\text {BC }}$ | － | － | 02 | － |
| H | 6 E | H | ？ | CA | $\bar{\square}$ |
| H | 2 E | h | $\geqslant$ | D1 | $\cdots$ |
| I | OC | 1 | $\leqslant$ | 98 | E |
| 1 | 20 |  |  |  |  |

Figure 17．Segment Codes for Various Characters Using 8 －Segment Displays（MSB of Hex Code is segment a， LSB is Decimal Point ie for $0(a=1, b=1, c=1, d=1, e=1, f=1, g=0, d p=0)=F C)$


Figure 18. Discrete and Numeric Display


Figure 19. Discrete LED Matrix Display


Figure 20. Dual 16 Element Bar Graph Display


Figure 21. Interfacing to Alphanumeric Displays


Figure 22. Multi-Digit Displays


Figure 23. 7-Segment Displays with 6-Discrete LED Indicators for MM74C912/MM74C917 Using "DP" Segment


Figure 24. MM74C917 (a) Display with 8 Discrete LED's (b) Inputs for LED Output Table
a


Figure 25. MM74C912 (a) 4 Digit Display with Discrete LEDs (b) I/O Data Table

## VIII. Interfacing To Microprocessors

The CMOS LED display controllers can be easily interfaced to most of the popular microprocessors with the addition of only a few ICs. Most microprocessor data and address bus logic is specified to be TTL compatible. A standard TTL logic high, $\mathrm{V}_{\mathrm{OH}}$ is supposed to be $\geqslant 2.4$ at full load which is not compatible with a CMOS $\mathrm{V}_{1 H} \geqslant 3.5 \mathrm{~V}$. Although microprocessor inputs will typically pull-up above 3.5 V , this is not guaranteed over the entire temperature range. It is recommended that pull-up resistors be added to raise this level above 3.5 V . Under most conditions, a $5-10 \mathrm{~K}$ resistor should suffice.

The write timing of the display controllers is illustrated in Figure 26. The minimum write access time is 430 ns for the MM74C912/MM74C917 and 450 ns for the MM74C911. A write to the controller is accomplished by placing the desired data on the data inputs, lowering the $\overline{\mathrm{CE}}$ and WE inputs, and then raising them to complete the write. Even though $\overline{\mathrm{CE}}$ and $\overline{\mathrm{WE}}$ are interchangeable, $\overline{\mathrm{CE}}$ is usually derived from the address decoding logic and $\overline{W E}$ is connected to the CPU write strobe. Other than the slight timing differences between
the MM74C911 and the MM74C912/MM74C917, the only other major microprocessor interfacing differences are that the MM74C912/MM74C917 have an additional digit address bit which must be connected to the microprocessors address bus, and the MM74C911 has eight data inputs whereas the MM74C912/MM74C917 have only five.

## A. Interfacing To The INS8080

These controllers can be connected to the INS8080/INS8224/INS8238 CPU group with no external logic if no more than a minimal amount of address decoding is required. Since the INS8080 has a separate memory and I/O port address spaces, one of the I/O port address bits could be directly connected to the CE input. Figure 27 illustrates this using an MM74C911. Whenever an OUT instruction is executed causing the I/OW (INS8080 write enable signal) to go low and the address is such that A7 is low, A0 A1 will select the digit to be written. If more decoding is required, some external gating logic may be added to the CE input.

The MM74C912/MM74C917 would be interfaced by connecting the A, B, C, D and DP to bit D0-D4 of the data bus and connecting $\mathrm{K} 1-\mathrm{K} 3$ to $\mathrm{A}_{0}-\mathrm{A}_{2}$. Writing data to these controllers would be the same as writing to the MM74C911

## B. Interfacing to the $\mathbf{Z 8 0}^{\text {m }}$ *

To connect these display controllers to the Z80 microprocessor, only a minor modification to the INS 8080 need be made. The Z80 control signals are slightly different from the INS8080. Instead of the INS8080 I/O write strobe, the Z80 has an I/O request line (IOREQ), which goes low to indicate an I/O port is to be accessed, and a write ( $\overline{W R}$ ) strobe which indicates that a memory or I/O write is to be done. By OR-ing, these together an equivalent $\overline{\mathrm{I}} \mathrm{OW}$ signal is generated as shown in Figure 28.

## C. Interfacing to the NSC800

The NSC800 has very different timing because the lower eight address bits and the data bus are multiplexed. But when connecting the display controllers as I/O ports, the interface is only slightly different from the INS8080 design. When an I/O instruction is executed, the port address that appears on A0-A7 is duplicated on A8-A15, and this address can be used directly. The controller $\overline{\mathrm{WE}}$ input must be decoded from a $\overline{\mathrm{WR}}$ (write enable) and $10 / \bar{M}$ (I/O or memory enable) as shown in Figure-29. Note that since the NSC800 is a CMOS microprocessor, no pull-up resistors are needed.

Figure 29 uses address bit A15 which is equivalent to bit A7 on the previous examples. As with the previous examples, if more address decoding is required, either gates or decoders could be connected to the CE input.

## D. Interfacing To The 6800

When using the INS8080, Z80, or NSC800, these processors have separate $1 / O$ and memory address spaces. This usually allows simpler interfaces to be designed. The 6800 has no separate I/O addressing so I/O ports are usually mapped into a small block of memory. This requires more address decoding to ensure that memory and I/O don't overlap.

Figure 30 shows a DM8131 6-bit address bus comparator whose $B_{n}$ inputs are a combination of A15-A12 address bits, the $\Phi_{2}(6800$ system clock) and the VMA (Valid Memory Access) control signal. When these inputs equal the corresponding $T_{n}$ inputs, the output goes low. The $6800 \mathrm{R} / \bar{W}$ signal is connected to the $\overline{W E}$.

## E. Interfacing To The INS8060/INS8070

Like the 6800, the INS8060/8070 series of microprocessors don't have any separate I/O addressing, so the MM74C911/MM74C912/MM74C917 must be memory addressed, but unlike the 6800 both the INS8070 series and the INS8060 have separate read/write strobes, which can simplify interfacing the display controllers. Figure 31 illustrates a typical INS8060 interface. The NWDS (write enable) is directly connected to the MM74C912s $\overline{W E}$ input and the DM8131 provides the address decoding for the controller. The INS8060 has only 12 address bits (unless using paged addressing) so bits $A_{6}-A_{11}$ are decoded by the comparator.
The INS8070 series microprocessor has the identical $\overline{\text { NWDS }}$ signal but has 16 address bits. Thus Figure 31 would connect the A10-A15 address bits to the DM8131.

Figure 26. MM74C911/MM74C912/MM74C917 Timing Diagram (See data sheets for numbers)


PORT ADDRESS = OXXX XXAB (BINARY)
(WHERE $X=$ DON'T CARE AND AB
ARE THE DIGIT SELECT ( $00-11$ )

Figure 27. INS8080/INS8224/INS8238 Interface to MM74C911


Figure 28. Z80 Interface to MM74C912/MM74C917


Figure 29. NSC800 Interface to MM74C911


Figure 30. MM74C911 to 6800 Microprocessor Interface


Figure 31. MM74C912/MM74C917 to INS8060 (SC/MP) Interface

## F. Multiple Display Controllers

In systems where multiple display controllers are to be used, the simple addressing schemes of the previous examples may prove to be too costly in I/O capabilities, so some extra decoding is necessary to derive the $\overline{\mathrm{CE}}$ signals. A typical method uses a 2-4 line decoder or a 3-8 line decoder. Whare the total time from a stable address to the write pulse goes inactive is $\geqslant 1 \mu \mathrm{~S}$, a CMOS decoder such as the MM74C42 or MM74C154 can be used, but if faster accessing is required, their LS equivalents should be employed.

Figure 32 shows a typical implementation of a 16 -digit display using half of a DM74LS139 decoder to provide the $\overline{C E}$ signals for each controller.

## G. Making The MM74C911/MM74C912/ MM74C917 Look Like RAM

So far, the discussion of addressing the controllers has been to separate the devices from memory, but there are certain advantages to not doing this. In many instances, microprocessor software requirements are such that data outputted to the controller also must be remembered by the microprocessor for later use. Since data cannot be read from the display controllers, the processor must also write the data in a spare register or
a memory location. This extra writing and "bookkeeping" software can be eliminated by addressing the MM74C911/MM74C912/MM74C917 over existing RAM. When data is written to the controller, it could also be stored in RAM simultaneously and can be read later by the CPU.

Figure 31 shows a simple example of this using an MM74C912 controller and two MM2114 $1 \mathrm{~K} \times 4$ memory chips. A DM74LS30 is used to detect when the last eight bytes of this memory is being accessed and enables the controller display. Thus, the last eight bytes of the RAM contains a duplicate copy of what the display controller is displaying.

## IX. Conclusion

All three controllers provide simple and inexpensive interfaces to multiplexed multidigit displays. These devices are particularly well suited to microprocessor environments, but any type of CMOS compatible control hardware can be used. The MM74C911/MM74C912/ MM74C917 can most easily drive common anode displays. By providing most of the multiplex circuitry into one low-cost integrated circuit, the burden of designing discrete multiplexing has been eliminated.


Figure 32. Multi-Digit Array


Figure 33. Display Controller Mapped Over RAM (5-10 K $\Omega$ Pull-up Resistors may be needed on MM74C912 inputs)

## Data Acquisition Using the ADC0816 and ADC0817 8-Bit AID Converter with On-Chip 16 Channel Multiplexer

## I. Introduction

The ADC0816 and ADC0817, CMOS 16-Channel Data Acquisition devices are selectable multi-input 8-bit A/D converters. In addition to a standard 8 -bit successive approximation type A/D converter, these devices contain a 16 channel analog multiplexer with 4 -bit latched address inputs. They include much of the circuitry required to build an 8 -bit accurate, medium through-put data acquisition system.

These two converters are similar to the ADC0808/ ADC0809 A/D converters except that the ADC0816/ ADC0817 have 16 analog inputs instead of 8 , and the multiplexer output and the A/D comparator input are externally available. (The ADC0808/ADC0809 connect these internally.) This feature is useful when connecting signal processing circuitry to the A/D. Also the ADC0816/ADC0817 have an expansion control pin to allow addition of more multiplexers, hence more input channels.

Figure 1. ADC0816/ADC0817 Functional Block Diagram

Figure 2 shows this addressing scheme. A multiplexer enable pin called Expansion Control (EC) is also provided. Taking this pin low will disable the on chip multiplexer, allowing other multiplexers to be used, thus expanding the number of inputs.

| ADDRESS | EXPANSION | SELECTED |
| :---: | :---: | :---: |
| D C B A | CONTROL | CHANNEL |
| 0000 | 1 | INO |
| 00001 | 1 | IN1 |
| 00010 | 1 | IN2 |
| 000111 | 1 | IN3 |
| $0 \begin{array}{llll}0 & 1 & 0 & 0\end{array}$ | 1 | IN4 |
| $0 \begin{array}{llll}0 & 1 & 0 & 1\end{array}$ | 1 | IN5 |
| $0 \begin{array}{llll}0 & 1 & 1 & 0\end{array}$ | 1 | IN6 |
| $\begin{array}{llll}0 & 1 & 1 & 1\end{array}$ | 1 | IN7 |
| 10000 | 1 | IN8 |
| 10001 | 1 | IN9 |
| 10010 | 1 | IN10 |
| $\begin{array}{llll}1 & 0 & 1 & 1\end{array}$ | 1 | IN11 |
| 11000 | 1 | - W12 |
| $1 \begin{array}{llll}1 & 1 & 0 & 1\end{array}$ | 1 | IN13 |
| 11110 | 1 | IN14 |
| $\begin{array}{llll}1 & 1 & 1 & 1\end{array}$ | 1 | IN15 |
| $\mathrm{X} \times \times \mathrm{X}$ | 0 | NONE |

Figure 2. Analog Input Selection Table
The output of the multiplexer usually feeds the input of the second major functional block, the A/D converter. This converter is a successive approximation type converter that is composed of a comparator, 256R type resistor ladder, successive approximation register (SAR), control logic, and output data latch.

Under normal operation the control logic of the A/D will first detect a positive going pulse on the START input. On the rising edge of this pulse the internal registers
are cleared, and will remain clear as long as START is high. When the START input goes low, the conversion is initiated. The control logic will cycle to the beginning of the next approximation cycle at which time End of Conversion goes low and the conversion is started. During a conversion, the control logic will select a tap on the resistor ladder, and route the signal through a transistor switch tree to the input of the comparator. The comparator will decide whether this tap voltage is higher or lower than the input signal and indicate this to the control logic. The control logic then decides which tap is to be selected next. Meanwhile, the SAR maintains a record of the conversion's progress. This algorithm takes 8 clock periods per approximation and requires 8 aproximations to convert 8 bits. Thus 64 clock periods are required for a complete conversion.
Once the entire conversion is completed the data in the SAR is loaded into the output register. This is a TRISTATE ${ }^{©}$ register which requires that its outputs be enabled by raising the Output Enable (OE or TRI-STATE) input. The data can then be read by the controlling logic.
During operation, the EOC output must be monitored to determine whether the device is actively converting or is ready to output data. Once the channel address is loaded, a positive going pulse on START will start the conversion and cause EOC to fall. When EOC goes high again the data is ready to be read, which, as was previously stated, is accomplished by raising the OE input. The data can be read any time prior to one clock period before the completion of the next conversion. The ADC0816/ADC0817 timing is shown in Figure 3. (See data sheet for exact specifications.)


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## III. Analog Input Designs

## A. Ratiometric Conversion

The external availability of both ends of the $256 R$ resistor ladder makes this converter ideally suited to use with ratiometric transducers. A ratiometric transducer is a conversion device whose output is proportional to some arbitrary full scale value. In other words, the actual value of the transducers output is of no great importance, but the ratio of this output to the full scale reference is valuable. For example, the potentiometric transducers of Figure 4 have this feature.
The prime advantage of these transducers is that an accurate reference is not required. However, the reference should be noise free because voltage spikes during a conversion could cause inaccurate results.

Perhaps the simplest method to obtain a reference would be to use a voltage already present in the system, the power supply. As shown in Figure 4 the 5 V supply can be easily conected as the reference, but care must be taken to reduce power supply noise. The supply lines should be well bypassed with filter capacitors and it is
recommended that separate PC board traces be used to route the 5 V and ground to the reference inputs and to the supply pins.

## B. Absolute Conversion

Absolute conversion refers to the use of transducers whose output value is not related to some other voltage. The "absolute" value of the transducer's output voltage is very important. This implies that the reference must be very accurately known to be able to accurately determine the value of the transducers output. Figure 5 shows a typical grounded reference connection using the LM336-5, 5 V reference. Note that ratiometric transducers can also be used in this application along with absolute transducers.

In most of the following applications either absolute or ratiometric transducers can be used. The only difference being that when absolute transducers are employed, more accurate references should be used.


Figure 4. Simple Ratiometric Converter Using Power Supply as Reference


Figure 5. Simple Absolute Converter Using LM336-5.0 Converter

## C. Reference Manipulation

In some small systems (particularly CMOS systems) where a reference is required, one can use the reference as a supply as shown in Figure 6. In this case the LM336-5 is used to generate the 5 V reference and also the 5 V supply. An unregulated supply greater than 5 V is required to allow the reference to operate. The series resistor, $R$, is chosen such that the maximum current needed by the system is supplied while keeping the LM336-5 in regulation. The value of this resistor is simply:

$$
R=\frac{V_{S}-V_{\text {REF }}}{I_{A D}+I_{T R}+I_{p}+I_{R}}
$$

where $\mathrm{V}_{\mathrm{S}}=$ unregulated supply voltage; $\mathrm{V}_{\mathrm{REF}}=$ reference voltage; $\mathrm{l}_{\mathrm{LAD}}=\mathrm{V}_{\mathrm{REF}} / 1 \mathrm{~K} \Omega$, resistor ladder current; $I_{T R}=$ transducer currents; $I_{p}=$ system power supply requirements; and $\mathrm{I}_{\mathrm{R}}=$ minimum reference current.

Figure 7 shows a simple method of buffering the references to provide higher current capabilities. This eliminates the $I_{p}$ term in the above equation. In Figures 5, 6, and 7, it is advisable to add some supply bypass capacitors to reduce noise, typically $0.1 \mu \mathrm{~F}$.

## D. Reference Voltage Variation

In some cases it is possible to eliminate the need for gain adjustments on the analog input signais by varying the $\operatorname{Ref}(+$ ) and Ref( - ) voltages to achieve various full scale ranges. The reference voltage can be varied from 5 V to about 0.5 volts with the one restriction that $\left[V_{\text {Ref( }+ \text { ) }}-V_{\text {Ref( }-)}\right] / 2=\left(V_{C C}-G N D\right) / 2 \pm 0.1$ volts. In other words, the center of the reference voltage must be within $\pm 0.1 \mathrm{~V}$ of mid-supply. The reason for this is that the reference ladder is taped by an $n$ or p-channel MOSFET switch tree. Offsetting the voltage at the center of the switch tree from $\mathrm{V}_{\mathrm{CC}} / 2$ will cause the transistors to incorrectly turn off, resulting in inaccurate and erratic con-
versions. However, if properly applied, this method can reduce parts counts as well as eliminate extra power supplies for the input buffers.
Figure 8 shows a simple supply centered reference where R1 and R2 offset $\operatorname{Ref}\left(+\right.$ ) and $\operatorname{Ref}(-)$ from $V_{C C}$ and Ground. An LM336, 2.5 V reference is shown here, but any reference between 0.5 V and 5 V can be used. For odd reference values the simple op amp scheme shown in Figure 9 can be used. Single power supply op amps such as the LM324's or LM10's would work well. R1, R2, and R3 form a resistor divider in which R1 and R3 center the reference at $\mathrm{V}_{\mathrm{CC}} / 2$ and R 2 can be varied to obtain the proper reference magnitude.

## E. Analog Channel Expansion

The ADC0816/ADC0817 have an expansion control (EC) pin which is actually a multiplexer enable. When this signal is low, all the switches are inhibited so that another signal can be applied to the comparator input. Additional channels can be implemented very simply, as shown in Figure 10. This design has expanded the number of channels from 16 to 32 . To address the channels, 5 address lines are required. The lower 4 bits are directly applied to the A/D's A, B, C, and D inputs. All 5 bits are also applied to an MM74C174 Hex "D" flip-flop which is used as an address latch for the two CD4051's. The 1Q, 2Q, and 3Q outputs of the MM74C174 feed the CD4051 address inputs 4Q and 5Q are gated to form enable signals for each CD4051. 5Q is also routed to the EC input to properly enable the A/D's multiplexer.

The CD4051s are used with a 5 V supply, so their specifications are very similar to the ADC8016/ADC0817 multiplexer. Thus, anything that can be done with the ADC0816/ADC0817 multiplexer can be done with the CD4051's. This includes making use of the previously discussed input designs as well as others.


Figure 6. Reference Used as Power Supply


Figure 7. Buffered Reference Used as Power Supply


Figure 8. Supply Centered Reference Using LM336 2.5V Reference


Figure 9. Supply-Centered Reference Using Buffered Resistor Divider


Data Acquisition Using the ADC0816 and ADC0817 8-Bit A/D Converter
with On-Chip 16 Channel Multiplexer - AN-258

Figure 10. Simple 32 Channel A/D Converter

## F. Differential Analog Inputs

An easy, and sometimes overlooked method for implementing a differential input scheme is shown in Figure 11. This approach actually implements the differential in software. All 16 channels are paired into positive and negative inputs. Then the controlling logic or microprocessor will convert each channel of a differential pair, load each result, and then subtract the two results. This method requires two single ended conversions to do one differential conversion, hence the effective differential conversion time is twice that of a single channel or a little over $200 \mu \mathrm{~s}$ ( $\mathrm{Ck}=640 \mathrm{kHz}$ ). The differential inputs should be stable throughout both of the conversions to produce accurate results.


Figure 11. Simple 8 Differential Channel Converter

A 16 channel differential system can be realized by modifying Figure 10. This is accomplished by changing the CD4051's addressing and adding a differential amplifier in between the multiplexer outputs and the comparator input. The select logic for the CD4051's has been modified to enable the switches to be selected in parallel with the ADC0816/ADC0817. The outputs of the three multiplexers are connected to a differential amplifier, composed of 2 inverting amplifiers with gain and offset trimmers. A dual op amp configuration of inverting amplifiers can more easily be trimmed and has less stringent feed-back resistor matching requirements, as compared to a single op amp design. The transfer equation for the dual op amp amplifier shown in Figure 12 is:

$$
V_{o}=\left[\frac{R_{2} R_{5}}{R_{1} R_{3}}\right] V_{1}-\left[\frac{R_{5}}{R_{4}}\right] V_{2}
$$

Propagation delay through the op amps should be considered to provide sufficient time between the analog switch selection and start conversion to allow the ana-
log signal at the comparator input to settle. Using the LF356 op amp, this delay should be about $5 \mu \mathrm{~s}$.

## G. Input Signal Buffering

There are three basic ranges of input signal levels that can occur when interfacing the ADC0816/ADC0817 to the "real world". These are: a) signals which exceed $V_{C C}$ and/or go below ground; b) signals whose input ranges are less than $\mathrm{V}_{\mathrm{CC}}$ and Ground, but are different than the reference range; c) and signals that have an input range that is equal to the reference range. Each of these situations require different buffering.

The last situation, case " $c$ " is usually trivial. No buffering is required unless the source impedance of the input signal is very high. If this is the case a buffer may be added between the multiplexer output and comparator input pins. If a high input impedance op amp is used, the input leakage looking from the multiplexer input can be greaily reduced. This circuit is shown in Figure 13. Using a buffer like this eliminates the necessity for large capacitors on the multiplexer inputs (explained later), but these buffers usually require two supplies and can contribute their own conversion errors.

If the input signal is within the supply, but the reference cannot be manipulated to conform to the full input range, the unity gain buffer of Figure 13 can be replaced by another op amp as shown in the Figure 13 inset. This type of amplifier will provide gain and/or offset control to create a full scale range equal to the reference.

The third case, $c$, where the input range exceeds $\mathrm{V}_{\mathrm{CC}}$ and/or goes below ground, the input signals must be level shifted before they can go to the multiplexer with the only exception being when the magnitude of the input voltage range is within 5 V , but outside the $0-5 \mathrm{~V}$ supply range. In this case the supply for the entire chip could be shifted to the analog input range, and the digital signals level shifted to the system's 5 V supply.

A typical example would be bipolar inputs from -2.5V to +2.5 . If the ADC0816/ADC0817 have their supply and reference derived as shown in Figure 14, then the $\pm 2.5 \mathrm{~V}$ logic outputs need only to be level shifted to 0 and 5 V logic levels, Figure 15.

## H. Digital Data Acquistion

The ADC0816/ADC0817 make good analog data acquisition subsystems, but there are many instances where these converters are good digital data acquisition systems as well. If a system has unused channels, digital inputs can be connected to these channels instead of being separately buffered into the system. In the case of a microprocessor system this could eliminate an I/O port and associated logic. The speed at which this input is accessed is one conversion cycle, but many times this will be fast enough. These inputs can be used as input switches, power supply indicator devices, or other system status flags. The microprocessor converts the digital input channel and reads it. Software then decides whether the input is high enough or low enough to cause a particular action.


Figure 12. Differential 16 Channel A/D Converter


Figure 13. Single Input Amplifier Buffering


Figure 14. $\pm 2.5 \mathrm{~V}$ Input Range Data Acquisition


（b）

Figure 15．Input／Output Level Shifters

## I．Input Considerations

In most instances interfacing analog circuitry is very straightforward，but there are some constraints that should be observed if a reliable accurate system design is to result．One major consideration，input source impedance is actually somewhat more complicated than it appears．One would expect that the input current would be a small D．C．current，but due to the nature of the comparator，it is not．The A／D＇s comparator is a capacitor sampling comparator whose input current is a series of spikes．Figure 16 shows a simplified model of the comparator input．

When determining a single bit value during a conver－ sion， S 1 will close causing $\mathrm{C}_{\mathrm{C}}$ and $\mathrm{C}_{\mathrm{p}}$ to charge to the input voltage．Then S 1 is opened and S 2 is closed samp－ ling the ladder．The input current is an RC transient charging current whose magnitude and duration is dependent on the values of $C_{c}, C_{p}, R_{s}, R_{m}$ and $R_{L}$ ．The duration of the transient must be shorter than the input sample period，and the sample period is dependent on the converter＇s clock frequency．Thus the maximum source impedance is dependent on the clock period．At a clock frequency of $1 \mathrm{MHz}, R_{s} \leqslant 1 \mathrm{k}$ ；and at $640 \mathrm{kHz}, R_{s} \leqslant$ 2 k ．The source impedance of potentiometric transdu－ cers vary as a function of wiper position．Thus transdu－ cers with a value of $\leqslant 10 \mathrm{k}$ at a frequency of 640 kHz and $\leqslant 5 \mathrm{k}$ at 1 MHz are suitable．

When a sample－and－hold or some other active device is inserted between the multiplexer and comparator pins， the output impedance of the transducers are no longer as restricted and depend more on the particular Samplel

Hold or op amp chosen．The critical parameter now is the source impedance of the buffer which should be $\leqslant$ 3 k at a clock frequency of 1 MHz and $\leqslant 5 \mathrm{k} \Omega$ with the clock equal to 640 kHz ．

If higher impedances are unavoidable，RC charging errors can be reduced to an average current error by placing a capacitor $=1 \mu \mathrm{~F}$ ，from the multiplexer input to ground．Adding this capacitor will average the transient current spikes and cause a small DC current error which for a potentiometric transducer is：

$$
V_{E R R}=\frac{R p}{8}\left(l_{1 N}\right) \frac{C k}{640 \mathrm{kHz}} \text { Volts }
$$

where $R p=$ total potentiometer resistance；$I_{\mathbb{N}}=2 \mu \mathrm{~A}$ （maximum input current at 640 kHz ）；and $\mathrm{Ck}=$ clock fre－ quency．For a standard buffer source impedance the voltage error is：

$$
V_{E R R}=I_{I N}\left(R_{S}\right) \frac{C k}{640 \mathrm{kHz}} \text { Volts }
$$

where $R_{S}=$ buffer source impedance；$I_{\mathbb{N}}=2 \mu \mathrm{~A}$（maxi－ mum average input current at 640 kHz ）；and $\mathrm{Ck}=$ clock frequency．

In addition，whenever analog signals are present in a digital system，several precautions should be exercised to reduce noise on the analog inputs．The analog input signals and the reference input should be kept physi－ cally isolated from the digital signals and a single point analog ground should be employed．

## J. Protecting the Analog Inputs Against Over Voltages

During nōrmal operation, it is important to keep the analog input voltages to the multiplexer or comparator between $\mathrm{V}_{\mathrm{CC}}$ and Ground to ensure proper operation. There may be some occasions where over or under voltages cannot be avoided. Protecting the analog inputs, due to their unique nature, can be more difficult than digital inputs. The most effective method is to use external Schottky diodes as shown in Figure 17a. Since the Schottky knee voltage is 0.4 volts the IN5166 diodes of Figure 17a will safely shunt currents up to several milliamps. To shunt possible currents larger than several milliamps some series resistance may be added to
limit these currents as shown in Figure 17b, but this value resistor must be no greater than the values speciied in the previous section.

A less expensive solution would be to replace the Schottky diode with some standard switching diodes, Figure 17b, but since these diodes could only partially shunt the input current from the internal clamp diodes, some series resistor should be used as in Figure 17c. If the external diode must shunt a large amount of current the two series resistors of Figure 17d should be used. If the input design is such that the input can exceed only one supply the diode going to the other supply can be omitted.

Figure 16. Simplified Multiplexer/Comparator Equivalent Circuit




Figure 17. Analog Input Protection Circuitry

## IV. Signal Conditioning

There are many applications where it is desirable to add some signal processing circuitry to improve circuit performance. Typical additions would be filter circuits, sample/holds, gain controlled amplifiers, and others. Here again the external accessibility of the multiplexer output and comparator input pins can greatly reduce the amount of circuitry required by enabling the use of only one circuit required by enabling the use of only one circuit all 16 outputs instead of 1 for each input.

## A. Gain Control

Previous examples of gain manipulation have dealt with one fixed gain for all 16 channels, but there are occasions where variable gain or selectable gain may improve accuracy and simplify hardware and/or software.

Figure 18 shows a typical method for gain control. The CD4051, analog multiplexer, is placed in the feedback loop of a simple non-inverting op amp. The gain of this op amp is controlled by selecting one of the CD4051's analog switches.

This will switch a resistor in and out of the feedback loop. If these resistors, $R_{2 N}$, are of different values, different gains are realized. These gains are given by:

$$
A_{V}=1+\frac{R_{2 N}}{R_{1}}
$$

A microprocessor or some control logic would select a gain by latching the channel address into a MM74C173. It is important to ensure the output of the LF356B does not exceed the power supply, so before a new channel is selected the gain of the op amp should be reduced to a safe value. The 1 k resistor on the output of the LF356 is to help protect the comparator inputs from accidental over or under voltages. Two back biased diodes placed from the input to $\mathrm{V}_{\mathrm{CC}}$ and Ground (IN914 or Schottky) will offer further protection.


Figure 18. Microprocessor Controlled Gain

## B. Sample/Holds

The only major data acquisition element not included on the ADC0816 is a sample/hold circuit. If the input signals are fast moving then a $\mathrm{S} / \mathrm{H}$ should be used to quickly acquire the signal and then hold it while the ADC0816/ADC0817 converts it. This circuit can be easily implemented by inserting it between the multiplexer output and the comparator input.

The simplest solution is to tie a capacitor on the multiplexer output and then tie this pin to the comparator input pin. The expansion control pin is used as a sample control. When this pin is high one switch is on and the capacitor voltage will follow the input. However, when the expansion control pin is pulled low, all switches are turned off and the capacitor holds its last value, almost. The input bias to the comparator is about $2 \mu \mathrm{~A}$ (worst case with $\mathrm{Ck}=640 \mathrm{KHz}$ ). Thus the droop rate for a 1000 pF is approximately $2000 \mathrm{~V} / \mathrm{S}$ or about $0.2 \mathrm{~V} / \mathrm{con}$ version. This is totally impractical. If a $0.01 \mu \mathrm{~F}$ capacitor is used instead then the droop rate is 20 mV , which may be satisfactory. Unfortunately, the acquisition time is on the order $100 \mu \mathrm{~S}$, or about the length of a conversion.

The problem is that the comparator input leakage is too high for this sample and hold. To eliminate this, the input can be buffered by using an LM356B. Figure 19. The leakage, now due mostly to multiplexer leakages, is reduced to approximately 100 nA . The droop per conversion is typically less than 1.0 mV per conversion when using a 1000 pF capacitor and the acquisition time is approximately $20 \mu \mathrm{~S}$.

A more accurate solution would be to isolate the capacitor from both the multiplexer comparator pins of the ADC0816/ADC0817. This is easily accomplished by using the LF398 monolithic sample/hold, as shown in

Figure 20. The acquisition time for this part is typically $4 \mu \mathrm{~S}$ to $0.1 \%$, and the droop rate is $20 \mu \mathrm{~V} /$ conversion. This circuit has its own hold control thus the expansion control is free to be used normally.

The choice of the hold capacitor is critical to the performance of the sample/hold circuit. Some capacitors are composed of dielectrics that will have an initial droop after the hold is strobed. This is due to dielectric absorption. Polypropylene and polystyrene dielectrics have very little dielectric absorption and thus make excellent sample/hold capacitors. Such materials as mylar polyethylene have higher absorption properties and should not be used.

## C. Filtering Analog Inputs

Under some conditions the analog input may have come from a noisy environment and to recapture the original signal some filtering may be required. Typically high frequency noise must be filtered. The ADC0816/ADC0817 can easily accommodate the addition of many standard low pass filters. Another useful filter is a 50 Hz or 60 Hz notch filter to eliminate the nose contributed to the circuit by A.C. power lines.
It is particularly easy to place a single passive filter between the multiplexer output and comparator input pins, but passive filters must be carefully desizned to reduce input loading. The filter capacitor will tend to average the comparator sampling current as mentioned in the Input Considerations section. To eliminate this, the passive filter can be buffered by an op amp or an active filter could be used.


Figure 19. Op Amp Sample Hold Circuit


Figure 20. Sample/Hold Converter Using LF398

## V. Microprocessor Interface

The interface requirements for the ADC0816/ADC0817 interconnection to various microprocessors are essentially the same as the ADC0808/ADC0809 requirements. The devices can be connected to the CPU so that it looks either like a memory location or I/O port. The data transfers can be initiated by either an interrupt to the CPU or the CPU can periodically interrogate the A/D. When trying to implement an absolute minimum components count system, the I/O port (as opposed to memory) addressing will usually require fewer components.

There are several design considerations that apply to most microprocessor systems when interfacing the ADC0816/ADC0817. Even though the actual timing of CPU read and write cycles vary, in general, a microprocessor will output the address and data (if write operation) onto its busses. A certain time later the Read or Write strobes will go active for a specified time. The interface logic must detect the state of the address and data busses and initiate the specified action. For the ADC0816/ADC0817 these actions are; 1) load channel address, 2) start conversion, 3) detect end of conversion and 4) read resultant data. These actions are performed by decoding the read/write strobes, address, and data information to form the and ALE and START pulses, then detect EOC, and finally read the data.

For the most part the decoding and strobe generation is straight forward. The START, ALE, and OE strobes will generally be of the same duration as the CPU read/write strobes and positive going (ALE can be negative going). One subtle choice is where to derive the $A, B, C$, and $D$ channel select address. These lines can be connected to either the address bus or the data bus. The advantage of connecting them to the data bus is that in minimum systems, more I/O address lines are available for simple decoding. When the A, B, C, and D inputs are connected to the address bus each analog channel becomes a separate I/O port.

In most designs it is very tempting to tie START and ALE together, enabling one pulse to both write the channel address and then start the conversion. However, it is very important that the signal on the comparator input be stable before the conversion starts, otherwise the first and most important successive approximation could be in error. Usually the START and ALE pulses are the same length as the CPU read and write strobes which are normally between 0.2 to $1 . \mu \mathrm{S}$ long. Thus the conversion may start within $1 \mu \mathrm{~S}$ of the address select latching. (Remember the channel is selected on the rising edge of ALE and the conversion begins within 8 clock periods of the falling edge of START.) For converter clocks greater than $500 \mathrm{KHz}, 1 \mu \mathrm{~S}$ may not be enough time to allow the analog input signal to propagate through the multiplexer and any additional signal conditioning circuitry such as buffers, S/H's, etc. There are, however, a couple of easy fixes that can correct this possible problem. First, the START/ALE pulse could be stretched to the proper length by using a one-shot (MM74C221 or similar) to generate a pulse as long as the total delay from multiplexer input to comparator input. Secondly, the problem can be circumvented by "double pulsing" the converter. This can be easily accomplished in software by writing to the START/ALE address twice. The first pulse latches the desired channel address and starts the conversion. The second pulse must again load the same channel address, which will not change the multiplexer's state, and will then restart the conversion. Of course, the second pulse must occur after the comparator input has settled.

Even though the hardware to interface the ADC0816/ADC0817 to various microprocessors will differ and the system software will vary, the basic routines to operate the ADC0816/ADC0817 are usually similar. There are many variations, but Figures 21 \& 22 illustrate flow charts that typify these routines. These routines
the ADC0816/ADC0817 is tied directly to the address and data bus (as opposed to using a peripheral controller). Generally, the hardware to create START and ALE pulses. This does not necessarily have to be true, but write instructions are conceptually easier and little is gained by designing the logic such that read instructions intiate these pulses. The OE pulse must be created by an I/O or memory read as the converter's data must be read.

The major design consideration is whether EOC should be polled by the microprocessor or whether EOC should cause an interrupt. This decision is system dependent, however the following applications illustrate both methods.


Figure 21. Flow Chart for Interrupt Control of ADC0816/ADC0817

## A. Interfacting to INS8080

Interfacing the ADC0816/ADC0817 to an INS8080 system is extremely simple, because the INS8080/ INS8224/INS8228 CPU group have separate I/O read ( $\overline{\mathrm{IOR}}$ ) and I/O write ( $\overline{(/ \mathrm{OW})}$ strobes which imply that the INS8080 has separate I/O addressing. In small systems this means that very little or no address decoding is necessary. Figure 23 shows a very simple interface which uses two NOR gates to gate the I/O strobes with the most significant address bit A7. The INS8080 has 8 bits of port address which will yield a maximum of 4 I/O ports if inputs $A, B, C$, and $D$ are connected to the address bus. A MM74C74 flip-flop is used as a divide-by-2 to generate a converter clock of 1 MHz . If the INS8080 system clock is $\leqslant 1 \mathrm{MHz}$ this flip-flop is unnecessary.


Figure 22. Flow Chart to Control ADC0816/ADC0817 in a Polled I/O Mode


Figure 23. Simple INS8080/8224/8228 to ADC0816/ADC0817 Interface

Typical software would first write the channel address to the converter and start it. As mentioned before, two start pulses should be sent to the ADC0816/ADC0817 to allow the comparator input to settle. After the second start pulse the CPU could execute other program segments until it is interrupted by EOC going high. Depending on the interrupt structure, program control would then be given to the interrupt handler which reads the converter's data.

The second interface circuit, Figure 24 utilizes a DM74LS139 dual 2-4 decoder in which one-half of the chip is used to create read pulses and the other half write pulses. The START and OE inputs are inverted to provide the correct pulse polarity. This interface partially decodes A6 and A7 to provide more I/O capabilities than before. This circuit also implements a simple polled I/O structure. The EOC output is placed on the data bus by a TRI-STATE ${ }^{\circledR}$ inverter when the inverter is enabled by an INS8080 read.

## B. Interfacing to the $\mathbf{Z 8 0}^{\text {™ }}$

The Z80m, even though architecturally similar to the INS8080, uses slightly different control lines to perform I/O reads and writes. In Figure 25 a NOR gate approach similar to Figure 22 is shown to interface the $Z 80$ to the ADC0816/ADC0817. Instead of $\overline{/ O R}$ and $\overline{/ / O W}$ strobes the $Z 80^{\text {TM }}$ has $\overline{R D}$ (read) and $\overline{W R}$ (write) strobes which are gated with $\overline{\text { OREQ (I/O request). In the } \mathrm{Z8O}}{ }^{\text {Tм }}$ interface, to show a slight variation, START is connected to OE instead of ALE. This will cause a new conversion to be started whenever the data is read which may seem z80 is a trademark of Zilog.
unusual, but can actually be useful if the converter is to be continually restarted upon completion of the previous conversion. Address bit A6 is used to derive a strobe which will place EOC on the data bus to be read by the CPU.

Figure 26 uses a 6 bit comparator to decode A4-A7 and IOREQ. Two NOR gates are used to gate the ALE/START and OE pulses. This design functions the same as Figure 23 except that the DM8131 provides much more decoding.

## C. Interfacing to the NSC800

The NSC800 interface is actually very similar to the INS8080 I/O interface, even though their timing is very different. The NSC800 multiplexes the lower 8 address bits on the data bus at the beginning of each cycle. When accessing memory, A0-A7 must be latched out at the beginning of a read or write cycle, but for I/O accessing; the NSC800 duplicates the 8 bit I/O addresses on A8-A15 address lines and latches are not necessary since these lines aren't multiplexed. The I/O read and write strobes are derived from a $\overline{R D}$ (read) and $\overline{W R}$ (write) line and the IO/M signal.

Figure 27 shows a design using a dual 2-4 line decoder which decodes A15, and A14 and is enabled by the read/write strobes. TRI-STATE ${ }^{\oplus}$ inverters are used to implement a scheme similar to Figure 24. This scheme has START and ALE accessed separately so that "double pulsing" isn't required.


NOTE: PULL-UP RESISTORS SHOULD BE
AdDED TO CMOS INPUTS TO IMPROVE TTL COMPATIBILITY

Figure 24. Partial Address Decoding INS8080/8224/8228 to ADC0816/ADC0817


Figure 25. Simple Z80 Interface to ADC0816/ADC0817


Figure 26. Decoded Z80 Interface
 ADDED TO CMOS INPUTS TO IMPROVE TTL COMPATIBILITY

Figure 27. Partially Decoded NSC800 to ADC0816/ADC0817 Interface

The next design, Figure 28, uses the same simple NOR gating scheme as Figure 23, except the NSC800 control signals are slightly different. A simple interrupt scheme for EOC is employed using an MM74C74. When EOC goes high the flip-flop is set and INTR goes low. When the NSC800 acknowledges the interrupt by lowering $\overline{I N T A}$, the flip-flop will reset. If more than one interrupt can occur simultaneously either INTA should be gated with EOC, or some other signal instead of INTA must be used. This is required since it is possible for the NSC800 to detect another interrupt and clear the ADC0816/ADC0817 interrupt before it's detected.

## D. Interfacing to the $\mathbf{6 8 0 0}$

The 6800 has no separate I/O addressing capabilities, so the system I/O must be addressed as though it is memory. As mentioned before, memory mapping can require more address decoding in order to separate memory from I/O, but in small systems very minimal parts count is still attainable.
Figure 29 illustrates an interface which uses a DM8131 comparator to partially decode the A12, A13, A14, and A15 address lines with the $\Phi_{2}$ clock and Valid Memory Address (VMA), to provide an address decode pulse for the two NOR gates which in turn generate the START/ALE Pulse and the output enable signal. This design will locate the AID in one 4k byte block.
This design tied EOC to $\overline{\mathrm{REQ}}$ interrupt through an inverter. This is only usable in single interrupt systems since the 6800 has no way of resetting this interrupt except by
starting a new conversion. Since EOC is directly tied to the interrupt input, the controlling software must not re-enable interrupts until 8 converter clock periods after the START pulse when EOC is low.

The memory control signals are very different from the INS8080 type CPU's. One line indicates whether the operation is a read or write, $R \bar{W}$ instead of separate read/write outputs on the INS8080/Z80/NSC800. This signal along with VMA indicate a valid read/write operation.

Figure 30 is slightly more complex, but provides more I/O port strobes. A NAND gate and inverter are used to decode the addresses, VMA and $\Phi_{2}$ clock. The I/O addresses are located at 1110XXXXXAABBBB (Binary); where X=don't care; $A=00$ (Binary) for ALE write or Data read and $A=01$ for START write or IREQ reset/EOC read; and $B=$ channel select address if $A, B, C$ and $D$ are connected to the address bus and ALE is accessed. A dual $2-4$ line decoderis used to generate these strobes and inverters are used tocreate the correct logic levels.

The 6800 supports only a wired-OR interrupt structure. In a multi-interrupt environment only one interrupt is received and the interrupt handler routine must determine which deveice has caused the interrupt and service that device. (Although the INS8080/Z80/NSC800 can implement a similar structure, hardware interrupt controllers can also be used which will automatically vector the $\mu \mathrm{P}$ to the correct service routine.) To do this EOC is brought out to the data bus so the CPU can check it.


Figure 28. Minimal NSC800 to ADC0816/ADC0817 Interface


Figure 29. $\mathbf{6 8 0 0}$ to ADC0816/ADC0817 Interíace


Figure 30. Partially Decoded 6800 to ADC0816/ADC0817 Interface

## E. Interfacing to the INS8060 or INS8070

Like the INS8080 type microprocessors the INS8060 (SC/MP) and INS8070 have separate read (NRDS) and write ( $\overline{\mathrm{NWDS}}$ ) strobes, but like the 6800 these microprocessors have no separate I/O addressing thus all I/O ports must be memory mapped. The INS8060 has 12 bits of direct addressing ( 16 bits with paged addressing) and may require less decoding that a 16 bit uP when not using more than one page. The INS8070 has a 16 bit address bus and will have similar decoding requirements as the 6800, except that there are no equivalent $\Phi_{2}$ or VMA signals.

Figure 31 shows an interface using the DM8131 bus comparator to decode A11-A6 address bits. The output of the DM8131 is gated with NRDS and NWDS to generate the START/ALE and OE strobes. START and ALE are tied together and should be pulsed twice to ensure a proper conversion. The EOC output is applied to the INS8060 SENSE A input. This input can be used as a polled input where its level can be determined by reading the $\mu \mathrm{P}$ status flag register. If the CPU's interrupt enable is set, then the SENSE A input becomes an active high interrupt input which will transfer control to the user's handler routine.

The INS8070 timing is very similar to the INS8060. Read (NRDS) and write (NWDS) enable lines are provided and since the INS8070 does not have separate I/O addressing, all I/O is memory mapped.

Figure 32 shows an interface where a DM74LS139 dual 2-4 decoder and DM74LS30 are used for address decoding. When NWDS is low, CPU writes to memory and 1Y0-1Y3 outputs will be decoded depending on A4 and A5 address lines. During a read operation NRDS will be low again enabling 1Y0-1Y3 outputs. The INS8070 also has SENSE inputs like the INS8060,


Figure 31. Simple INS8060 (SC/MP) to ADC0816/ADC0817


Figure 32. Simple INS8070 Interface to ADC0816/ADC0817

The application of digital systems to detect weight provides for low cost, accurate weight scales.

A developed system using the $33 / 4$-digit DVM IC, ADD3701,* shown in figure 1, allows for conversion of an analog voltage to digital information linearly related to the weight being sensed.

Support circuitry for the DVM IC consists of a voltage regulator, a reference voltage, a weight sensing element, display drivers, and an LED display. Additional circuitry may be implemented for added features.
The weight scale circuit of figure 1 employs a potentiometer as the weight sensing element and functions as
a variable voltage divider from ground to $\mathrm{V}_{\text {REF }} 2$ volts. An object placed upon the scale displaces the potentiometer wiper, which is connected to the scale mechanics, an amount proportional to its weight. Conversion of the wiper voltage to digital information is performed, decoded, and interfaced to the numeric display by the ADD3701. The LM340 regulates the $\mathrm{V}_{\mathrm{CC}}$ supply voltage and the RA07 resistor array is connected as a voltage divider to generate the ADD3701 2 V reference voltage. The NSB7881 is driven by the ADD3701 segment drivers and the DS8976 digit drivers.
*See ADD3701 data sheet for details of DVM operation.


## Notes:

1. R1, C1 defines POWER ON display blanking interval. R2, C2 defines display ON time.
2. All $V_{C C}$ connections should use a single $V_{C C}$ point and all ground/analog ground connections should use a single ground/analog ground point.
3. Display sequence for Rev A ckt implementation:
$t=0 \mathrm{sec} \quad-$ power $O N$
$\mathrm{t}=0 \rightarrow 5 \mathrm{sec}$ - display blanked

- system converging
$t=5 \rightarrow 10 \mathrm{sec}$ - conversion complete
- display ENABLE
$t \geqslant 10 \mathrm{sec} \quad-$ display blanked
- wait for new POWER UP cycle

Figure 1

Q2, the MM74C02 and surrounding circuitry generate the display sequence explained in Note 3 of figure 1.

The ADD3701 3 3 3 -digit DVM displays a maximum of 3999 counts, full scale, having a resolution of $500 \mu \mathrm{~V}$ per LSD.

With the decimal point of digit 3 forced "ON" by Q1 the maximum displayed reading of figure 1 would equate to 399.9 units of weight.

Figure 2 is a weight scale sensor similar to that in figure 1, differing only in the weight sensing element and its related support circuitry.

The transformer of figure 2 is rectified to a DC voltage, proportional to a weight displacement, and then converted to its digital equivalent with the ADD3701.

The purpose of setting analog ground two diode drops above digital ground is to help cancel the inherent air coupling offset voltage generated by the transformer.

Figure 2 is also connected to display a maximum of 399.9 units of weight. The accuracy of both systems without the transducer elements is $\pm 1 \mathrm{LSD}$ at $25^{\circ} \mathrm{C}$ $\pm 15^{\circ} \mathrm{C}$.

## Notes:

1. Excitation to the LVDT (i.e., outputs of the MM74C93 and MM74C74) may be altered to compensate for the varying frequency ranges of LVDTs.
2. All $V_{C C}$ connections should use a single $V_{C C}$ point and all ground/analog ground connections should use a single ground/analog ground point.

Figure 2


A CMOS key encoder combines with a couple of Dual D flip-flops and an exclusive OR package to form a simple but versatile programmable divider. The input frequency can be divided by any number $n$ between 1 and 16 by simply pressing the appropriate key. The counter output is symmetrical for both odd and even divisors.

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This circuit is useful for simple frequency synthesis or as an oscilloscope triggering unit where the displayed signal is applied to the counter input and the external trigger of the oscilloscope is connected to the counter output. The trigger signal is then some submultiple of displayed signal which often results in a more stable trace. Different divisors can be easily keyed in as the input signal varies.


Simply press the key and the input frequency is divided by that number. The output frequency is symmetrical for odd and even divisors. Use it for simple frequency synthesis or as a keyboard controlled oscilloscope triggering unit.

The key encoder scans the key array which is set up so the key labeled " 16 " is in the matrix position which causes " 0 " to be encoded, the key labeled " 15 " causes " 1 " to be encoded, and so on until we find that the key position labeled " 1 " causes a binary " 15 ," or all ones, at the output of the encoder. The key arrangement converts a key position so that any number $n$ from 1 to 16 is encoded as $16-\mathrm{n}$ at the encoder output. For example, if the key labeled 5 is pressed the binary number 1011=11 appears at the encoder output. The MM74C922 key encoder scans the keys, detects, debounces, and encodes any entry. An internal register remembers the last key pressed and presents it to the Tri-State ${ }^{\circledR}$ outputs.

The input to the exclusive OR is a "zero" when the respective encoder output is a "zero" or when the feedback signal from the last counter stage forces the encoder outputs into Tri-State. When in Tri-State the pull down resistors feed a "zero" into the exclusive OR inputs.
When the output is an active "one," the clock signal from one flip-flop to the next is inverted by the exclusive ORs.

When the output is a "zero" or the encoder is in Tri-State, due to the feedback signal, the clock signal from one flipflop to the next is the same phase. For every $n / 2$ input time period, the counter output and feedback change state. Whenever the feedback signal changes state, all flip-flops programmed with a "one" by the encoder change their phases; this effectively adds a clock pulse to that stage of the counter. The addition of clock pulses to the $2^{0}, 2^{1}, 2^{2}$ or $2^{3}$ stages allows us to divide by any number between 1 and 16 . Since the feedback changes state every $\mathrm{n} / 2$ input time period, the output frequency is symmetrical for any divisor.
The unit operates over the standard CMOS supply range of 3 to 15 volts and has a typical upper frequency limit of one megacycle with a 10 volt supply.

## REFERENCE

1. M. V. Subba Rao, "Programmable Divide by $n$ Counter Provides Symmetrical Outputs for all Divisors," Electronic Design, no. 2, January 19, 1976, p. 82.

# MM54C/MM74C Voltage Translation/Buffering 

## INTRODUCTION

A new series of MM54C/MM74C buffers has been designed to interface systems operating at different voltage levels. In addition to performing voltage translation, the MM54C901/MM74C901 through MM54C904/MM74C904 hex buffers can drive two standard TTL loads at $V_{c C}=5 \mathrm{~V}$. This is an increase of ten times over the two LpTTL loads that the standard MM54C/MM74C gate can drive. These new devices greatly increase the flexibility of the MM54C/MM74C family when interfacing to other logic systems.

## PMOS TO CMOS INTERFACE

Since most PMOS outputs normally can pull more negative than ground, the conventional CMOS input diode clamp from input to ground poses problems. The least of these is increased power consumption. Even though the output would be clamped at one diode drop ( -0.6 V ), all the current that flows comes from the PMOS negative supply. For TTL compatible PMOS this is -12 V . A PMOS output designed to drive one TTL load will typically sink

5 mA . The total power per TTL output is then $5 \mathrm{~mA} \times 12 \mathrm{~V}=60 \mathrm{~mW}$. The second problem is more serious. Currents of 5 mA or greater from a CMOS input clamp diode can cause four-layer diode action on the CMOS device. This, at best, will totally disrupt normal circuit operation and, at worst, will cause catastrophic failure.

To overcome this problem the MM74C903 and MM74C904 have been designed with a clamp diode from inputs to $\mathrm{V}_{\mathrm{Cc}}$ only. This single diode provides adequate static discharge protection and, at the same time, allows voltages of up to -17 V on any input. Since there is essentially no current without the diode, both the high power dissipation and latch up problems are eliminated.

To demonstrate the above characteristics, Figures 1, 2, and 3 show typical TTL compatible PMOS circuits driving standard CMOS with two clamp diodes, TTL compatible PMOS driving MM74C903/MM74C904, and the TTL compatible PMOS to CMOS system interface, respectively.


FIGURE 1.


FIGURE 2.


FIGURE 3. PMOS to CMOS or TTL Interface

## CMOS TO CMOS OR TTL INTERFACE

When a CMOS system which is operating at $\mathrm{V}_{\mathrm{cc}}=10 \mathrm{~V}$ must provide signals to a CMOS system whose $\mathrm{V}_{\mathrm{cc}}=5 \mathrm{~V}$, a problem similar to that found in PMOS-to-CMOS interface occurs. That is, current would flow through the upper input diode of the device operating at the lower $\mathrm{V}_{\mathrm{Cc}}$. This current could be in excess of 10 mA on a typical 74C device, as shown in Figure 4. Again, this will cause increased power as well as possible four layer diode action.


FIGURE 4.


FIGURE 5.
Using the MM74C901 or MM74C902 will eliminate this problem. This occurs simply because these parts are designed with the upper diode removed, as shown in

Figure 5. With this diode removed the current being sourced goes from about 10 mA to the leakage current of the reverse biased input diode.

Since the MM74C901 and MM74C902 are capable of driving two standard TTL loads with only normal input levels, the output can be used to directly drive TTL. With the example shown, the inputs of the MM74C901 are in excess of 5 V . Therefore, they can drive more than two TTL loads. In this case the device would drive four loads with $V_{\text {IN }}=10 \mathrm{~V}$. If the MM74C902 were used, the output drive would not increase with increased input voltage. This is because the gate of the output n-channel device is always being driven by an internal inverter whose output equals that of $\mathrm{V}_{\mathrm{CC}}$ of the device.

The example used was for systems of $\mathrm{V}_{\mathrm{cc}}=10 \mathrm{~V}$ on one system and $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ on the second, but the MM74C901 and MM74C902 are capable of using any combination of supplies up to 15 V and greater than 3 V , as long as $\mathrm{V}_{\mathrm{CC} 1}$ is greater than or equal to $\mathrm{V}_{\mathrm{CC} 2}$ and grounds are common. Figure 6 diagrams this configuration.


FIGURE 6. CMOS to TTL or CMOS at a Lower $\mathrm{V}_{\mathrm{CC}}$

The inputs on these devices are adequately protected with the single diode, but, as with all MOS devices, normal care in handling should be observed.

## Section 9

## Ordering and Package Information

|  | ring In | ation <br> MM74C S |  |  |
| :---: | :---: | :---: | :---: | :---: |
| Order <br> Number |  | Package |  | Temperature Range |
| MM74CXXN |  | Molded DIP (N) |  | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| MM74CXXJ |  | Cavity DIP (J) |  | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| MM54CXXJ |  | Cavity DIP (J) |  | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM54CXXD |  | Cavity DIP (D) |  | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM54CXXW |  | Cavity Flat Pack |  | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM80CXXN |  | Molded DIP (N) |  | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| MM80CXXJ |  | Cavity DIP (J) |  | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| MM70CXXJ |  | Cavity DIP (J) |  | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM70CXXD |  | Cavity DIP (D) |  | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| MM70CXXW |  | Cavity Flat Pack |  | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD4000 Series |  |  |  |  |
| Order Number | RCA <br> Equivalent Designation | Motorola Equivalent Designation | Package | Temperature Range |
| CD40XXCN | CD40XXAE | MC140XXCP | Molded DIP (N) | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| CD40XXCJ | CD40XXAY | MC140XXCL | Cavity DIP (J) | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| CD40XXMJ | CD40XXAF | MC140XXAL | Cavity DIP (J) | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD40XXMD | CD40XXAD |  | Cavity DIP (D) | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD40XXMW | CD40XXAK |  | Cavity Flat Pack (W) | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD40XXBCN | CD40XXBE | MC140XXBCP | Molded DIP (N) | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| CD40XXBCJ | CD40XXBY | MC110XXBCL | Cavity DIP (J) | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| CD40XXBMJ | CD40XXBF | MC140XXBAL | Cavity DIP (J) | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD40XXBMD | CD40XXBD |  | Cavity DIP (D) | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| CD40XXBMW | CD40XXBK |  | Cavity Flat Pack (W) | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| *CD40XXCN | CD45XXBE | MC145XXBCP | Molded DIP (N) | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| *CD45XXCJ | CD45XXBY | MC145XXBCL | Cavity DIP (J) | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| *CD45XXMJ | CD45XXBF | MC145XXBCP | Cavity DIP (J) | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| *CD45XXMD | CD45XXBD |  | Cavity DIP (D) | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| *CD45XXMW | CD45XXBK |  | Cavity Flat Pack (W) | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |

## *Equivalent to Motorola MC145XX Series

## Dual-in-Line Packages

( N ) Devices ordered with the " N " suffix are supplied in plastic molded dual-in-line packages. Molding material is a highly reliable compound suitable for military as well as commercial temperature range applications. Lead material is copper or alloy 42 with a hot solder dipped surface to allow ease of solderability.
( J ) Devices ordered with the " J " suffix are supplied in cer-dip packages (ceramic lid and base sealed with a high temperature vitreous glass). Lead material is solder dipped alloy 42.
(D) Devices ordered with the " $D$ " suffix are supplied in side braze, multi-layered ceramic dual-in-line packages. The leads are Kovar or alloy 42 and either tin-plated, gold-plated, or solder-plated.
so6eyoed SOWO

CMOS Packages
All dimensions expressed as $\frac{\text { inches }}{\text { millimeters }}$


18-Lead Hermetic Dual-In-Line Package (D) NS Package Number D18A


20-Lead Hermetic Dual-In-Line Package (D) NS Package Number D20A


28-Lead Hermetic Dual-In-Line Package (D) NS Package Number D28A


40-Lead Hermetic Dual-In-Line Package (D)
NS Package Number D40C


14-Lead Hermetic Dual-In-Line Package (J) NS Package Number J14A


16-Lead Hermetic Dual-In-Line Package (J) NS Package Number J16A


20-Lead Hermetic Dual-In-Line Package (J) 22-Lead Hermetic Dual-In-Line Package (J) NS Package Number J22A


24-Lead Hermetic Dual-In-Line Package (J) NS Package Number J24A


8-Lead Molded Mini Dual-In-Line Package (N) NS Package Number N08A


14-Lead Molded Dual-In-Line Package (N) NS Package Number N14A


16-Lead Molded Dual-In-Line Package (N) NS Package Number N16A


18-Lead Molded Dual-In-Line Package ( N ) NS Package Number N18A



24-Lead Molded Dual-In-Line Package ( $N$ ) NS Package Number N24A


28-Lead Molded Dual-In-Line Package ( N ) NS Package Number N28A


40-Lead Molded Dual-In-Line Package (N)
NS Package Number N40A

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Telex: K24942


[^0]:    No change in output from previous state.

[^1]:    $H=$ high level, $L=$ low level

[^2]:    ${ }^{1}$ Shiftung left requires external connection of $O_{B}$ to $A, O_{C}$ to $B$, and $Q_{D}$ to $C$. Serial data is entered at input $D$
    $H=$ high level (steady state), $L=$ low level (steady state), $X=$ irretevant (any input, including transitions)
    i $=$ transition from high to low level, $1=$ transition from low to high level
    $a_{A O}, a_{B 0}, a_{C O}, a_{D O}=$ the level of $a_{A}, a_{B}, a_{C}$, or $a_{D}$, respectively, before the indicated steady-state input conditions were established.
    $\mathrm{a}_{A n}, \mathrm{a}_{\mathrm{B}} . \mathrm{a}_{\mathrm{C}} . \mathrm{a}_{\mathrm{Dn}}=$ the level of $\mathrm{a}_{\mathrm{A}}, \mathrm{a}_{\mathrm{B}}, \mathrm{a}_{\mathrm{C}}$. or $\mathrm{a}_{\mathrm{D}}$. respectivety, before the most-recent I transition of the clock

[^3]:    PARALLEL INPUTS

[^4]:    *Output 5-6 only
    **Output 1-4 only
    $X=$ Irrelevant

[^5]:    $X=$ represents TRI-STATE condition

[^6]:    * Each segment to backplane with 200 pF capacitor.

[^7]:    *Master/slave selecton is arbitrary and dependent only on which oscillator pin is grounded.

[^8]:    *     * To correctly implement leading zero blanking the least significant device must be the master.

[^9]:    *Master/slave selection is arbitrary and dependent only on which oscillator pin is grounded.

[^10]:    TRI-STATE ${ }^{*}$ is a registered trademark of National Semiconductor Corp.

[^11]:    * The logic diagram for the MM54C921/MM74C921 is identical to this except that data inputs (DI1-D14) are connected to data outputs (DO1-DO4).

[^12]:    * Symbols in parentheses are proposed industry standard.

    TRI-STATE ${ }^{\oplus}$ is a registered trademark of National Semiconductor Corp.

[^13]:    * Symbols in parentheses are proposed industry standard.

[^14]:    * Symbols in parentheses are proposed industry standard.

[^15]:    * Precede $\bar{W}$ rising edge with $\bar{E}$ rising edge to avoid unwanted output enabling

[^16]:    * TWLWH, the write pulse, is the coincidence low of $\bar{E}, \bar{W}$, and $\overline{S 1}$ inputs

[^17]:    * Avoid bus contention

[^18]:    Note 1: This device should not be connected to circuits with the power on because high transient voltages may cause permanent damage.

[^19]:    $X=$ irrelevant
    $\mathrm{NC}=$ no change
    $=$ Low to High level transition
    $=$ High to Low level transition

[^20]:    * Don't Care condition.

[^21]:    H = High level
    L = Low level
    $\mathrm{X}=$ Irrelevant
    $\uparrow=$ Transition from low to high level
    $\mathrm{NC}=$ No change

    * $=\overline{\mathrm{Q}}$ for CD40175B only

[^22]:    Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.
    Note 2: $\mathrm{V}_{\mathrm{SS}}=O \mathrm{~V}$ unless otherwise specified.
    Note 3: CPD determines the no load ac power consumption of any CMOS device. For complete explanation, see 54C/74C Family Characteristics application note, AN-90.

[^23]:    $\Gamma=$ positive transition
    = negative transition
    $\mathrm{X}=$ don't care

[^24]:    $\emptyset=$ Don't care
    Hi-Z = TRI-STATE® condition
    $X_{n}=$ Data at input $n$

[^25]:    Display 9.999 when overflowed. All digits can also be blanked at overflow by tying OFL to BI on the CD4543's

[^26]:    Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.
    Note 2: Unless otherwise specified min/max limits apply across the $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ temperature range for the DS78C20 and across the $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ range for the DS88C20. All typical values are for $T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$.
    Note 3: All currents into device pins shown as positive, out of device pins as negative, all voltages referenced to ground unless otherwise noted.
    All values shown as max or min on absolute value basis.
    Note 4: Only one output at a time should be shorted.
    Note 5: Refer to EIA-RS-422 for exact conditions.

[^27]:    *DESC Status Codes
    1-Spec in negotiation
    2-Currently qualifying supplier
    3-New input - will advise
    4-No current plans for slash sheet

[^28]:    ${ }^{1}$ One rad (Si) is the quantity of any type of ionizing radiation which imparts 100 ergs of energy per gram of silicon.

[^29]:    ${ }^{2}$ W.R. Dawes, Jr., G.F. Derbenwich and B.L. Gregory, "Process Technology for Radiation Hardened CMOS Integrated Circuits," IEEE Journal of Solid State Circuits, SC-11, No. 4, p. 459, August 1976.

[^30]:    ＊Functional failures

[^31]:    ＊Assumes interfacing to low power TTL．
    ＊＊Assumes interfacing to CMOS．

[^32]:    ＊W．R．Dawes，Jr．，G．F．Derbenwich and B．L．Gregory，＂Process Technology for Radiation Hardened CMOS Integrated Circuits，＂ IEEE Journal of Solid State Circuits，Sc－11，No．4，p．459，August 1976.

[^33]:    TRI-STATE ${ }^{*}$ is a registered trademark of National Semiconductor Corp.

